

Robert A. Evarestov

Quantum Chemistry of Solids

LCAO Treatment of Crystals
and Nanostructures

2nd Edition



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and Nanostructures

Second Edition

With 128 Figures



Springer

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*This book is dedicated to my teacher
and friend Professor Marija I. Petrashen*

Preface to the Second Edition

The first edition of this monograph was published in 2007 and appeared to be useful for solid-state scientists in different countries. This is confirmed by numerous references to this monograph in recently published scientific papers. It gave me great pleasure to know that a second enlarged edition of my book was planned by Springer-Verlag.

In the second edition of the book fresh applications of the LCAO method to solids have been added. In particular, two new chapters are included in the Part II of the book.

Chapter 12 deals with the recent LCAO calculations of the bulk and surface properties of crystalline uranium nitrides and illustrates the efficiency of scalar-relativistic LCAO method for solids containing heavy atoms.

Chapter 13 deals with the symmetry properties and the recent applications of the LCAO method to inorganic nanotubes based on BN, TiO_2 and SrTiO_3 compounds. The efficiency of first-principles LCAO calculations for predicting the structure and stability of single- and double-wall nanotubes is demonstrated.

New material is also added to Chap. 9 devoted to LCAO calculations of perfect-crystal properties. ABO_3 -type oxides such as barium titanate BaTiO_3 are attractive for various technological applications in modern electronics, nonlinear optics, and catalysis. We demonstrate that the use of hybrid exchange correlation functional allows reproducing the equilibrium volumes and structural, electronic, dielectric, and vibrational properties of paraelectric cubic and three ferroelectric (tetragonal, rhombohedral, and orthorhombic) BaTiO_3 phases in good agreement with the existing experimental data. It is also shown that the use of the first-principles LCAO approach allows the calculation of BaTiO_3 thermodynamic properties, which provides the valuable information on the low temperature behavior that is not easy to obtain by experimental techniques.

The efficiency of the LCAO method in the quantum-mechanics–molecular dynamics approach to the interpretation of x-ray absorption is illustrated using perovskite as an example.

A new section is devoted to recent LCAO calculations of electronic, vibrational, and magnetic properties of tungstates MeWO_4 (Me: Zn, Ni).

The list of references is extended to include papers, published in 2007–2011 and devoted to the application of the LCAO method to the first-principles calculations of crystals and nanostructures.

This second edition of the book would not be possible without the help of Prof. M. Cardona, who encouraged me of writing the first edition and gave me useful advice.

I am grateful to Prof. C. Pisani and members of the Torino group of Theoretical Chemistry, Prof. R. Dovesi, Prof. C. Roetti, for many years of fruitful cooperation. Very sadly my colleagues and friends Prof. C. Pisani and Prof. C. Roetti passed away recently. I will never forget their role in my professional life.

I am grateful to all my colleagues who took part in our joint research (Prof. V. Smirnov, Prof. K. Jug, Prof. T. Bredow, Prof. J. Maier, Prof. E. Kotomin, Prof. Ju. Zhukovskii, Prof. J. Choynet, Prof. G. Borstel, Prof. F. Illas, Prof. A. Dobrotvorsky, Prof. A. Kuzmin, Prof. J. Purans, Dr. V. Lovchikov, Dr. V. Veryazov, Prof. I. Tupitsyn, Dr. A. Panin, Dr. A. Bandura, Dr. D. Usvyat, Dr. D. Gryaznov, Dr. V. Alexandrov, Dr. D. Bocharov, Dr. A. kalinko, and E. Blokhin) or sent me fresh results of their research (Prof. C. Pisani, Prof. R. Dovesi, Prof. C. Roetti, Prof. P. Deak, Prof. P. Fulde, Prof. G. Stoll, Prof. M. Schütz, Prof. A. Schluger, Prof. L. Kantorovich, Prof. C. Minot, Prof. G. Scuseria, Prof. R. Dronskowski, Prof. A. Titov, and Dr. B. Aradi).

I would like to express my thanks to the members of the Quantum Chemistry Department of St. Petersburg State University, Dr. A. Panin and Dr. A. Bandura, for their help in preparing the second edition of the book.

I am especially indebted to Dr. C. Ascheron of Springer-Verlag for the encouragement and cooperation in the preparation of this edition.

It goes without saying that I am alone responsible for any shortcomings which remain.

St. Petersburg, Russia
April 2012

Robert A. Evarestov

Preface to the First Edition

Nobel Prize Winner Prof. Roald Hoffmann introducing a recently published book by Dronskowski [1] on computational chemistry of solid-state materials wrote that one is unlikely to understand new materials with novel properties if one is wearing purely chemical or physical blinkers. He prefers a coupled approach—a chemical understanding of bonding merged with a deep physical description. The quantum chemistry of solids can be considered as a realization of such a coupled approach.

It is traditional for quantum theory of molecular systems (molecular quantum chemistry) to describe the properties of a many-atom system on the grounds of interatomic interactions applying the linear combination of atomic orbitals' (LCAO) approximation in the electronic-structure calculations. The basis of the theory of the electronic structure of solids is the periodicity of the crystalline potential and Bloch-type one-electron states, in the majority of cases approximated by a linear combination of plane waves (LCPW). In a quantum chemistry of solids the LCAO approach is extended to periodic systems and modified in such a way that the periodicity of the potential is correctly taken into account, but the language traditional for chemistry is used when the interatomic interaction is analyzed to explain the properties of the crystalline solids. At first, the quantum chemistry of solids was considered simply as the energy-band theory [2] or the theory of the chemical bond in tetrahedral semiconductors [3]. From the beginning of the 1970s the use of powerful computer codes has become a common practice in molecular quantum chemistry to predict many properties of molecules in the first-principles LCAO calculations. In the condensed-matter studies the accurate description of the system at an atomic scale was much less advanced [4].

During the last 10 years this gap between the molecular quantum chemistry and the theory of the crystalline electronic structure has become smaller. The concepts of standard solid-state theory are now compatible with an atomic-scale description of crystals. There are now a number of general-purpose computer codes allowing prediction from the first-principles LCAO calculations of the properties of crystals. These codes are listed in Appendix C. Nowadays, the quantum chemistry of solids can be considered as the original field of solid-state theory that uses the methods

of molecular quantum chemistry and molecular models to describe the different properties of solid materials including surface and point-defect modeling.

In this book we have made an attempt to describe the basic theory and practical methods of modern quantum chemistry of solids.

This book would not have appeared without the help of Prof. M. Cardona who supported the idea of its writing and gave me useful advice.

I am grateful to Prof. C. Pisani and members of the Torino group of Theoretical Chemistry, Prof. R. Dovesi, Prof. C. Roetti, for many years of fruitful cooperation. Being a physicist-theoretician by education, I would never have correctly estimated the role of quantum chemistry approaches to the solids without this cooperation. I am grateful to all my colleagues who took part in our common research (Prof. V. Smirnov, Prof. K. Jug, Prof. T. Bredow, Prof. J. Maier, Prof. E. Kotomin, Prof. Ju. Zhukovskii, Prof. J. Choisnet, Prof. G. Borstel, Prof. F. Illas, Dr. A. Dobrotvorsky, Dr. V. Lovchikov, Dr. V. Veryazov, Dr. I. Tupitsyn, Dr. A. Panin, Dr. A. Bandura, Dr. D. Usvyat, Dr. D. Gryaznov, and V. Alexandrov) or sent me the recent results of their research (Prof. C. Pisani, Prof. R. Dovesi, Prof. C. Roetti, Prof. P. Deak, Prof. P. Fulde, Prof. G. Stoll, Prof. M. Schütz, Prof. A. Schluger, Prof. L. Kantorovich, Prof. C. Minot, Prof. G. Scuseria, Prof. R. Dronskowski, and Prof. A. Titov). I am grateful to Prof. I. Abarenkov, head of the Prof. M.I. Petrashen named seminar for helpful discussions and friendly support. I would like to express my thanks to the members of the Quantum Chemistry Department of St. Petersburg State University, Dr. A. Panin and Dr. A. Bandura, for help in preparing the manuscript—without their help this book would not be here.

I am especially indebted to Dr. C. Ascheron, Mrs. A. Lahee, and Dr. P. Capper of Springer-Verlag for encouragement and cooperation.

St. Petersburg, Russia
August 2006

Robert A. Evarestov

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Part I

Theory

Chapter 1

Introduction

Prof. P. Fulde wrote in the preface to the first edition of his book [5]: Monographs are required that emphasize the features common to quantum chemistry and solid-state physics. The book by Fulde presented the problem of electron correlations in molecules and solids in a unified form. The common feature of these fields is also the use of the LCAO (linear combination of atomic orbitals) approximation: being from the very beginning the fundamental principle of molecular quantum chemistry, LCAO only recently became the basis of the first-principles calculations for periodic systems. The LCAO methods allow one to use wavefunction-based (Hartree–Fock), density-based (DFT), and hybrid Hamiltonians for electronic-structure calculations of crystals. Compared to the conventional plane-wave (PW) or muffin-tin orbital (MTO) approximations, the LCAO approach has proven to be more flexible. To analyze the local properties of the electronic structure, the LCAO treatment may be applied to both periodic- and molecular-cluster (nonperiodic) models of solid. Furthermore, post-Hartree–Fock methods can be extended to periodic systems exhibiting electron correlation. LCAO methods are able to avoid an artificial periodicity typically introduced in PW or MTO for a slab model of crystalline surfaces. The LCAO approach is a natural way to extend to solid-state procedures of the chemical bonding analysis developed for molecules. With recent advances in computing power, LCAO first-principles calculations are possible for systems containing many (hundreds) atoms per unit cell. The LCAO results are comparable with the traditional PW or MTO calculations in terms of accuracy and variety of accessible physical properties. More than 30 years ago, it was well understood that the quantum theory of solids based on LCAO enabled solid-state and surface chemists to follow the theoretically based papers that appeared [2]. As an introduction to the theory of the chemical bond in tetrahedral semiconductors, the book [3] (translation from the Russian edition of 1973) appeared. Later, other books [6] and [7] appeared. These books brought together views on crystalline solids held by physicists and chemists. The important step in the computational realization of the LCAO approach to periodic systems was made by scientists from the Theoretical Chemistry Group of Turin University

(C. Pisani, R. Dovesi, C. Roetti) and the Daresbury Computation Science Department in England (N.M. Harrison, V.R. Saunders) with their coworkers from different countries who developed several versions of the CRYSTAL computer code—(88, 92, 95, 98, 03, 06) for the first-principles LCAO calculations of periodic systems. This code is now used by more than 200 scientific groups all over the world. Many results applying the above code can be found in the book published about 10 years ago by Springer: [4]. The publication includes review articles on the Hartree–Fock LCAO approach for application to solids written by scientists actively working in this field. The book by Fulde mentioned earlier takes the next step to bridge the gap between quantum chemistry and solid-state theory by addressing the problem of electron correlations. During the next 10 years, many new LCAO applications were developed for crystals, including the hybrid Hartree–Fock–DFT method, full usage of the point and translational symmetry of periodic system, new structure optimization procedures, applications to research related to optical and magnetic properties, study of point defects and surface phenomena, and generation of the localized orbitals in crystals with application to the correlation effects study. Also, LCAO allowed the development of $O(N)$ methods that are efficient for large-size many-atom periodic systems. Recently published books including [8–11] may be considered as the high-quality modern text books. The texts provide the necessary background for the existing approaches used in the electronic-structure calculations of solids for students and researchers. Published in the Springer Series in Solid State Sciences (vol. 129), a monograph [12] introduces all the existing theoretical techniques in materials research (which is confirmed by the subtitle of this book: From Ab initio to Monte Carlo Methods). This book is written primarily for materials scientists and offers to materials scientists access to a whole variety of existing approaches. However, to our best knowledge, a comprehensive account of the main features and possibilities of LCAO methods for the first-principles calculations of crystals is still lacking. We intend to fill this gap and suggest a book reflecting the state of the art of LCAO methods with applications to the electronic-structure theory of periodic systems. Our book is written not only for the solid-state and surface physicists, but also for solid-state chemists and materials scientists. Also, we hope that graduate students (both physicists and chemists) will be able to use it as an introduction to the symmetry of solids and for comparison of LCAO methods for solids and molecules. All readers will find the description of models used for perfect and defective solids (the molecular-cluster, cyclic-cluster, and supercell models; models of the single and repeating slabs for surfaces; the local properties of the electronic-structure calculations in the theory of the chemical bonding in crystals). We hope that the given examples of the first-principles LCAO calculations of different solid-state properties will illustrate the efficiency of LCAO methods and will be useful for researchers in their own work. This book consists of two parts: theory and applications. In the first part (theory), we give the basic theory underlying the LCAO methods applied to periodic systems. The translation symmetry of solids and its consequence is discussed in connection with a so-called cyclic (with periodic boundary conditions) model of an infinite crystal. For chemists, it allows clarification of why the $\mathbf{k}$ -space introduction is necessary

in the electronic-structure calculations of solids. The site-symmetry approach is considered briefly (it is given in more detail in [13]). The analysis of site symmetry in crystals is important for understanding the connection between one-particle states (electron and phonon) in free atoms and in a periodic solid. To make easier the practical LCAO calculations for specific crystalline structures, we explain how to use the data provided on the Internet sites for crystal structures of inorganic crystals and irreducible representations of space groups. In the next chapters of Part I, we give the basics of Hartree–Fock and Kohn–Sham methods for crystals in the LCAO representation of crystalline orbitals. It allows the main differences between the LCAO approach realization for molecules and periodic systems to be seen. The hybrid Hartree–Fock–DFT methods were only recently extended from molecules to solids, and their advantages are demonstrated by the LCAO results on bandgap and atomic structure for crystals.

In the second part (applications) we discuss some recent applications of LCAO methods to calculations of various crystalline properties. We consider, as is traditional for such books, the results of some recent band-structure calculations and also the ways of local properties of electronic-structure description with the use of LCAO or Wannier-type orbitals. This approach allows chemical bonds in periodic systems to be analyzed, using the well-known concepts developed for molecules (atomic charge, bond order, atomic covalency, and total valency). The analysis of models used in LCAO calculations for crystals with point defects and surfaces and illustrations of their applications for actual systems demonstrate the efficiency of LCAO approach in the solid-state theory. A brief discussion about the existing LCAO computer codes is given in Appendix C.

Chapter 2

Space Groups and Crystalline Structures

The classification of the crystalline electron and phonon states requires the knowledge of the full symmetry group of a crystal (space group G) and its irreducible representations. The group G includes both translations, operations from the point groups of symmetry and combined operations. The application of symmetry transformations means splitting all space into systems of equivalent points known also as Wyckoff positions in crystals, irrespective of whether there are atoms in these points or not. The crystal-structure type is specified when one states which sets of the Wyckoff positions for the corresponding space group are occupied by atoms. To distinguish between different structures of the same type, one needs the numerical values of lattice parameters and additional data if there exist occupied Wyckoff positions with free parameters in the coordinates. We briefly discuss the 15 crystal-structure types ordered by the space-group index. Among them are structures with both symmorphic and nonsymmorphic space groups, structures with the same Bravais lattice and crystal class but different space groups, and structures described by only lattice parameters or by both the lattice parameters and free parameters of the Wyckoff positions occupied by atoms.

2.1 Translation and Point Symmetry of Crystals

2.1.1 *Symmetry of Molecules and Crystals: Similarities and Differences*

Molecules consist of positively charged nuclei and negatively charged electrons moving around them. If the translations and rotations of a molecule as a whole are excluded, then the motion of the nuclei, except for some special cases, consists of small vibrations about their equilibrium positions. Orthogonal operations (rotations through symmetry axes, reflections in symmetry planes and their combinations) that transform the equilibrium configuration of the nuclei of a molecule into itself are

called the symmetry operations of the molecule. They form a group F of molecular symmetry. Molecules represent systems from finite (sometimes very large) numbers of atoms, and their symmetry is described by so-called point groups of symmetry. In a molecule, it is always possible to so choose the origin of coordinates that it remains fixed under all operations of symmetry. All the symmetry elements (axes, planes, inversion center) are supposed to intersect in the origin chosen. The point symmetry of a molecule is defined by the symmetry of an arrangement of atoms forming it, but the origin of coordinates chosen is not necessarily occupied by an atom.

In modern computer codes for quantum-chemical calculations of molecules, the point group of symmetry is found automatically when the atomic coordinates are given. In this case, the point group of symmetry is only used for the classification of electronic states of a molecule, particularly for knowledge of the degeneracy of the one-electron energy levels. To make this classification, one needs to use tables of irreducible representations of point groups. The latter are given both in books [13–15] and on an Internet site [16]. Calculation of the electronic structure of a crystal (for which a macroscopic sample contains 10^{23} atoms) is practically impossible without the knowledge of at least the translation symmetry group. The latter allows the smallest possible set of atoms included in the so-called primitive unit cell to be considered. However, the classification of the crystalline electron and phonon states requires knowledge of the full symmetry group of a crystal (space group). The structure of the irreducible representations of the space groups is essentially more complicated, and use of existing tables [17] or the site [16] requires knowledge of at least the basics of space-group theory.

Discussions of the symmetry of molecules and crystals are often limited to the indication that under operations of symmetry, the configuration of the nuclei is transformed to itself. The symmetry group is known when the coordinates of all atoms in a molecule are given. Certainly, the symmetry of a system is defined by a geometrical arrangement of atomic nuclei, but operations of symmetry translate all equivalent points of space to each other. In equivalent points, the properties of a molecule or a crystal (electrostatic potential, electronic density, etc.) are all identical. It is necessary to remember that the application of symmetry transformations means splitting all space into systems of equivalent points irrespective of whether there are atoms in these points or not. In both molecules and in crystals, the symmetry group is the set of transformations in three-dimensional space that transforms any point of the space into an equivalent point. The systems of equivalent points are called orbits of points (This has nothing to do with the orbitals—the one-electron functions in many-electron systems). In particular, the orbits of equivalent atoms in a molecule can be defined as follows. Atoms in a molecule occupy the positions $\mathbf{q}$ with a certain site symmetry described by some subgroups $F_{\mathbf{q}}$ of the full point-symmetry group F of a molecule. The central atom (if one exists) has a site-symmetry group $F_{\mathbf{q}} = F$. Any atom on the principal symmetry axis of a molecule with the symmetry groups C_n , C_{nv} , S_n also has the full symmetry of the molecule ($F_{\mathbf{q}} = F$). Finally, $F_{\mathbf{q}} = F$ for any atom lying in the symmetry plane

of a molecule with the symmetry group $F = C_s$. In other cases, F_q is a subgroup of F and includes those elements R of point group F that satisfy the condition $Rq = q$. Let F_1 be a site-symmetry group of a point q_1 in the molecular space. This point may not be occupied by an atom. Let the symmetry group of a molecule be decomposed into left cosets with respect to its site-symmetry subgroup F_q :

$$F = \sum_j R_j F_j, \quad R_j = E, \quad j = 1, 2, \dots, t \quad (2.1)$$

The set of points $q_j = R_j q_1$ $j = 1, 2, \dots, t$, forms an orbit of the point q_1 .

The point q_j of the orbit has a site-symmetry group $F_j = R_j F R_j^{-1}$ isomorphic to F_1 . Thus, an orbit may be characterized by a site group F_1 , (or any other from the set of groups F_j). The number of points in an orbit is equal to the index $t = n_F / n_{F_j}$ of the group F_j in F .

If the elements R_j in (2.1) form a group P then the group F may be factorized in the form $F = P F_j$. The group P is called the permutation symmetry group of an orbit with a site-symmetry group F_j (or orbital group).

In a molecule, all points of an orbit may be either occupied by atoms of the same chemical element or vacant. Only the groups C_n , C_{nv} , C_s may be site-symmetry groups in molecules. A molecule with a symmetry group F may have F as a site-symmetry group only for one point of the space (e.g., for the central atom). For any point-symmetry group a list of possible orbits (and corresponding site groups) can be given. In this list some groups may be repeated more than once. This occurs if in F there are several isomorphic site-symmetry subgroups differing from each other by the principal symmetry axes C_n , twofold rotation axes U perpendicular to the principal symmetry axis or reflection planes. All the atoms in a molecule may be partitioned into orbits.

Example. The list of orbits in the group $F = C_{4v}$ is

$$F_q = C_{4v}(1), \quad C_s(4), \quad C_1(8) \quad (2.2)$$

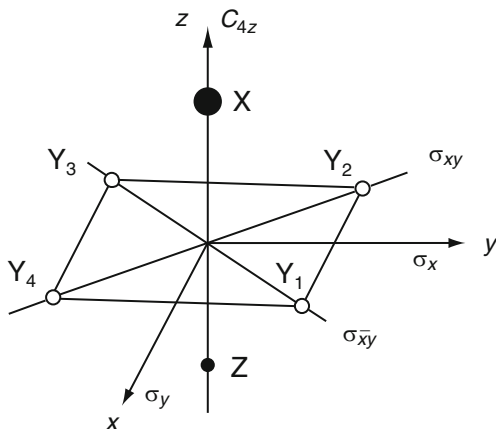
The number of atoms in an orbit is given in brackets. For example, in a molecule XY_4Z (see Fig. 2.1) the atoms are distributed over three orbits: atoms X and Z occupy positions on the main axis with site-symmetry $F = C_{4v}$ and four Y atoms occupy one of the orbits with site-symmetry group C_s . The symmetry information about this molecule may be given by the following formula:

$$C_{4v}[C_{4v}(X,Z), \quad C_s(Y)] \quad (2.3)$$

which indicates both the full symmetry of the molecule (in front of the brackets) and the distribution of atoms over the orbits. For molecules IF_5 and XeF_4O (having the same symmetry C_{4v}) this formula becomes

$$C_{4v}[C_{4v}(I,F), \quad C_s(F)] \quad \text{and} \quad C_{4v}[C_{4v}(Xe,O), \quad C_s(F)] \quad (2.4)$$

Fig. 2.1 Tetrahedral molecule XY_4Z



As we can see, atoms of the same chemical element may occupy different orbits, *that is*, may be nonequivalent with regard to symmetry.

In crystals, systems of equivalent points (orbits) are called Wyckoff positions. As we shall see, the total number of possible splittings of space of a crystal on systems of equivalent points is finite and for the three-dimensional periodicity case equals 230 (number of space groups of crystals). The various ways of filling of equivalent points by atoms generate a huge (hundreds of thousands) number of real crystalline structures.

As well as molecules, crystals possess point symmetry, *that is*, equivalent points of space are connected by the point-symmetry transformations. But in a crystal, the number of the point-symmetry elements (the rotation axis or reflection planes) is formally infinite. Therefore, it is impossible to find such a point of space where all the point-symmetry elements intersect. It is connected by the fact that, unlike molecules, in crystals among operations of symmetry, there are translations of a group of rather small number of atoms to space. The presence of translation symmetry means the periodicity of the perfect crystals structure: translations of the primitive unit cell reproduce the whole crystal.

In real crystals of macroscopic sizes translation, symmetry, strictly speaking, is absent because of the presence of borders. If, however, we consider the so-called bulk properties of a crystal (e.g., distribution of electronic density in the volume of the crystal, determining the nature of a chemical bond), the influence of borders cannot be taken into account (number of atoms near to the border is small, in comparison with the total number of atoms in a crystal), and we consider a crystal as a boundless system, [13].

In the theory of electronic structure, two symmetric models of a boundless crystal are used: it is supposed that the crystal fills all the space (model of an infinite crystal), or the fragment of a crystal of finite size (e.g., in the form of a parallelepiped) with the identified opposite sides is considered. In the second case, we say that the crystal is modeled by a cyclic cluster which translations as

a whole are equivalent to zero translation (Born–von Karman periodic boundary conditions—PBC). Between these two models of a boundless crystal, there exists a connection: the infinite crystal can be considered as a limit of the sequence of cyclic clusters with increasing volume. In a molecule, the number of electrons is fixed as the number of atoms is fixed. In the cyclic model of a crystal, the number of atoms (and thus the number of electrons) depends on the cyclic-cluster size and becomes infinite in the model of an infinite crystal. It makes changes, in comparison with molecules, to a one-electron density matrix of a crystal that now depends on the sizes of the cyclic cluster chosen (see Chap. 4). As a consequence, in calculations of the electronic structure of crystals, it is necessary to investigate convergence of results with an increase of the cyclic cluster that models the crystal. For this purpose, the features of the symmetry of the crystal, connected with the presence of translations, also are used.

In the theory of electronic structure of crystals, we also use the molecular-cluster model: being based on physical reasons, we choose a molecular fragment of a crystal and somehow try to model the influence of the rest of a crystal on the cluster chosen (e.g., by means of the potential of point charges or a field of atomic cores). From the point of view of symmetry, such a model possesses only the symmetry of point group due to which it becomes impossible to establish a connection of molecular-cluster electronic states with those of a boundless crystal. At the same time, with a reasonable molecular-cluster choice, it is possible to describe well enough the local properties of a crystal (e.g., the electronic structure of impurity or crystal imperfections). As an advantage of this model, it may also be mentioned an opportunity of application to crystals of those methods of the account of electronic correlation that are developed for molecules (see Chap. 5).

The set of operations of symmetry of a crystal forms its group of symmetry G called a space group of symmetry. Group G includes both translations, operations from point groups of symmetry, and also the combined operations. The structure of space groups of symmetry of crystals and their irreducible representations is much more complex than in the case of point groups of symmetry of molecules. Without knowledge of some basic data from the theory of space groups, it is impossible even to prepare inputs for computer codes to calculate the electronic structure of a crystal. These data will be briefly stated in the following sections.

2.1.2 Translation Symmetry of Crystals. Point Symmetry of Bravais Lattices. Crystal Class

Translation symmetry of a perfect crystal can be defined with the aid of three noncoplanar vectors: $\mathbf{a}_1, \mathbf{a}_2, \mathbf{a}_3$ basic translation vectors. Translation t_a through the lattice vector

$$\mathbf{a} = n_1\mathbf{a}_1 + n_2\mathbf{a}_2 + n_3\mathbf{a}_3 \quad (2.5)$$

where n_1, n_2, n_3 are integers, relates the equivalent points $\mathbf{r}$ and $\mathbf{r}'$ of the crystal

$$\mathbf{r}' = \mathbf{r} + \mathbf{a} \quad (2.6)$$

Translations t_a are elements of the translation group T . If we draw all the vectors $\mathbf{a}$ from a given point (the origin), then their endpoints will form the Bravais lattice, or “empty” lattice, corresponding to the given crystal. The endpoints of the vectors in this construction are the lattice points (lattice nodes). Three of the basic translation vectors define the elementary parallelepiped called the primitive unit cell (PUC). The PUC contains lattice points only at the eight corners of the parallelepiped. Each corner belongs to eight PUC, so that by fixing the PUC by one lattice point at the corner, we refer the remaining of the corners to the nearest seven PUCs. We note that the basic translation vectors cannot be chosen uniquely. However, whatever the choice of these vectors, the volume of the PUC is always the same. The PUC defines the smallest volume whose translations form the whole Bravais lattice (direct lattice). Usually, the basic vectors are chosen to be the shortest of all those possible. Atoms of a crystal are not necessarily located in the direct lattice points. In the simplest case, when all the crystal is obtained by translations of one atom (such crystals are termed monoatomic; many metals belong to this type), all atoms can be placed in direct lattice points.

As a set of points, the direct lattice possesses not only translation but also point symmetry, *that is*, lattice points are interchanged when rotations around one of the axes of symmetry, reflections in planes of symmetry, and their combinations are applied. All the point-symmetry operations of the Bravais lattice are defined when the origin of the coordinate system is chosen in one of the lattice points. The corresponding PUC can be defined as the reference unit cell (it is obtained by a zeroth translation ($n_1 = n_2 = n_3 = 0$ in (2.5)). Among point-symmetry operations of a direct lattice, it is obligatory to include inversion I in the origin of coordinates since, together with translation on a vector $\mathbf{a}$, the group of translations T also includes translation on a vector $-\mathbf{a}$. The identity element of group T is t_0 —a zeroth translation. Elements R of point group F^0 transform each lattice vector into a lattice vector: $R\mathbf{a} = \mathbf{a}'$. The point group F^0 of symmetry of the direct lattice determines the crystal system (or syngony). There are seven systems (syngonies) of direct lattices. It turns out that not all point groups can be lattice symmetry groups F^0 . The requirement that both $\mathbf{a}$ and $R\mathbf{a}$ can simultaneously be lattice vectors restricts the number of possible point groups. Let us now establish these limitations [18].

To establish the rotations of the group F^0 , let us take the basic lattice vectors $\mathbf{a}_1, \mathbf{a}_2, \mathbf{a}_3$ as the basis unit vectors in the space of the lattice vectors $\mathbf{a}$, and write down the matrix $D(R)$ of the transformation R in the new basis, in which all the lattice vectors have integer components. If the matrix of the orthogonal transformation R in this basis is denoted by $D'(R)$, then $D'(R) = U^{-1}D(R)U$, where U is a matrix of the transformation from the initial orthonormal basis to the basis $\mathbf{a}_1, \mathbf{a}_2, \mathbf{a}_3$. If R is a rotation (or mirror rotation) through an angle φ , the traces of the matrices $D(R)$ and $D'(R)$ are equal:

$$\text{Sp}D'(R) = \text{Sp}D(R) = \pm 1 + 2\cos(\varphi) \quad (2.7)$$

Since, however, R should transform the lattice vector $\mathbf{a}$ into the lattice vector $\mathbf{a}' = R'\mathbf{a}$, it follows that all the elements of $D'(R)$, and hence its trace, must be integers. It follows that $\cos(\varphi) = \cos(2\pi \frac{m}{n}) = \pm 1, \pm 2, 0$. Consequently, the group F^0 can contain only two-, three-, four-, and sixfold axes. Finally, it can be shown that if the group F^0 contains the subgroup C_n , $n > 2$, it will also contain the subgroup C_{nv} . The above three limitations ensure that the point group of the lattice can only be one of the seven point groups: $S_2, C_{2h}, D_{2h}, D_{3h}, D_{4h}, D_{6h}, O_h$. This is why there are only seven syngonies: namely, triclinic, monoclinic, orthorhombic, rhombohedral, tetragonal, hexagonal, and cubic. It is seen that, unlike molecules, in point groups of symmetry of crystals, there is no axis of symmetry of the fifth order (rotations around such axes are incompatible with the presence of translations).

Two Bravais lattices with the same group of point symmetry F^0 fall into one type if they can be transferred to each other by the continuous deformation that is not decreasing the point symmetry of a lattice. In three-dimensional space, there are 14 types of direct lattices whose distribution on syngonies is shown in Table 2.1. In addition to the translational subgroup T , the space group contains other transformations whose form depends on the symmetry of the Bravais lattice and the symmetry of the components of the crystal, *that is*, on the symmetry of the PUC as the periodically repeating set of particles forming the crystal. This last fact frequently ensures that not all the transformations in the point group F^0 are included in the symmetry group of the crystal. Not all transformations that map the sites on each other need result in a corresponding mapping of the crystal components. It is therefore possible that the point group of a crystal F (crystal class) will only be a subgroup of a point group of an empty lattice. So the real crystal-structure point-symmetry group F may coincide with the lattice point-symmetry group F^0 or be its subgroup. The distribution of crystal classes F and Bravais lattices on syngonies is given in Table 2.1.

The lattice types are labeled by P (simple or primitive), F (face-centered), I (body-centered), and $A(B, C)$ (base-centered). Cartesian coordinates of basic translation vectors written in units of Bravais lattice parameters are given in the third column of Table 2.1. It is seen that the lattice parameters (column 4 in Table 2.1) are defined only by syngony, *that is*, are the same for all types of Bravais lattices with the point symmetry F^0 and all the crystal classes F of a given syngony.

The point-symmetry group of a *triclinic* lattice Γ_1 (Fig. 2.2) consists of only inversion in the coordinates origin.

Therefore, this lattice is defined by 6 parameters—lengths a, b, c of basic translation vectors and angles α, β, γ between their pairs $\mathbf{a}_2 - \mathbf{a}_3, \mathbf{a}_1 - \mathbf{a}_3$ and $\mathbf{a}_1 - \mathbf{a}_2$, respectively.

In simple Γ_m and base-centered Γ_m^b *monoclinic* lattices, one of the vectors (with length c , for example) is orthogonal to the plane defined by two vectors with length a and b (γ is the angle between these vectors not equal to 90 or 120°). In lattice Γ_m^b the centered face can be formed by a pair of nonorthogonal lattice vectors. For example, in a C -centered monoclinic lattice, the lattice point appears on the face formed by $\mathbf{a}_1$ and $\mathbf{a}_2$ basic translation vectors. In the base-centered lattice,

Table 2.1 Distribution of crystal classes F and Bravais lattices on sygonies F^0

Syngony F^0 : Crystal classes F :	Direct lattice types	Basic translation vectors	Bravais lattice param.
Triclinic S_2 : $C_1, S_2(C_i)$	P	Any noncoplanar	$a, b, c,$ α, β, γ
Monoclinic C_{2h} : C_s, C_2, C_{2h}	P A, B, C	$(0, -b, 0), (a \sin \gamma, -a \cos \gamma, 0), (0, 0, c)$ $(0, -b, 0), (1/2)(a \sin \gamma, -a \cos \gamma, -c),$ $(1/2)(a \sin \gamma, -a \cos \gamma, c)$	a, b, c, γ
Orthorhombic D_{2h} : C_{2v}, D_2, D_{2h}	P A, B, C F I	$(0, -b, 0), (a, 0, 0), (0, 0, c)$ $(1/2)(a, -b, 0), (1/2)(a, b, 0), (0, 0, c)$ $(1/2)(a, 0, c), (1/2)(0, -b, c), (1/2)(a, -b, 0)$ $(1/2)(a, b, c), (1/2)(-a, -b, c), (1/2)(a, -b, -c)$	a, b, c
Tetragonal D_{4h} : $S_4, D_{2d}, C_4, C_{4v},$ C_{4h}, D_4, D_{4h}	P I	$(a, 0, 0), (0, a, 0), (0, 0, c)$ $(1/2)(-a, a, c), (1/2)(a, -a, c), (1/2)(a, a, -c)$	a, c
Hexagonal D_{6h} : $C_3, S_6, C_{3v}, C_{3h}, D_3,$ $D_{3d}, D_{3h}, C_6, C_{6h},$ C_{6v}, D_6, D_{6h}	H	$(a/2, -a/2, 0), (0, a, 0), (0, 0, c)$	a, c
Rhombohedral D_{3d} : $C_3, S_6, C_{3v}, D_3, D_{3d}$	R	$(a, 0, c), (-a/2, a/2, c), (-a/2, -a/2, c)$	a, c
Cubic O_h : T, T_d, T_h, O, O_h	P F I	$(a, 0, 0), (0, a, 0), (0, 0, a)$ $(1/2)(0, a, a), (1/2)(a, 0, a), (1/2)(a, a, 0)$ $(1/2)(-a, a, a), (1/2)(a, -a, a), (1/2)(a, a, -a)$	a

one can consider so-called conventional unit cell—the parallelepiped, reflecting the monoclinic symmetry of the lattice. For a simple monoclinic lattice Γ_m , the conventional and primitive unit cells coincide; for a base-centered monoclinic lattice Γ_m^b , the conventional unit cell contains 2 primitive unit cells (see Fig. 2.2).

All the three translation vectors of a simple *orthorhombic* lattice Γ_o are orthogonal to each other, so that the conventional cell coincides with the primitive cell and is defined by three parameters—lengths of the basic translation vectors. For base-centered Γ_o^b , face-centered Γ_o^f , and body-centered Γ_o^v lattices, the conventional unit cell contains two, four, and two primitive cells, respectively (see Fig. 2.2).

The *tetragonal* lattices Γ_q (simple) and Γ_q^v (body-centered) are defined by two parameters, as two of the three orthogonal translation vectors of a conventional unit cell have the same length a .

The *hexagonal* lattice is defined by two parameters: a —length of two equal basic translation vectors (with the angle 120° between them) and c —length of the third basic translation vector orthogonal two the plane of first two vectors.

In a *rhombohedral(triclinic)* lattice, all three translation vectors have the same length a , and all three angles α between them are equal (but differ from 90°), so this lattice is defined by two parameters. There are two possibilities to define the rhombohedral lattice parameters. In the first case, the parameters a and γ are

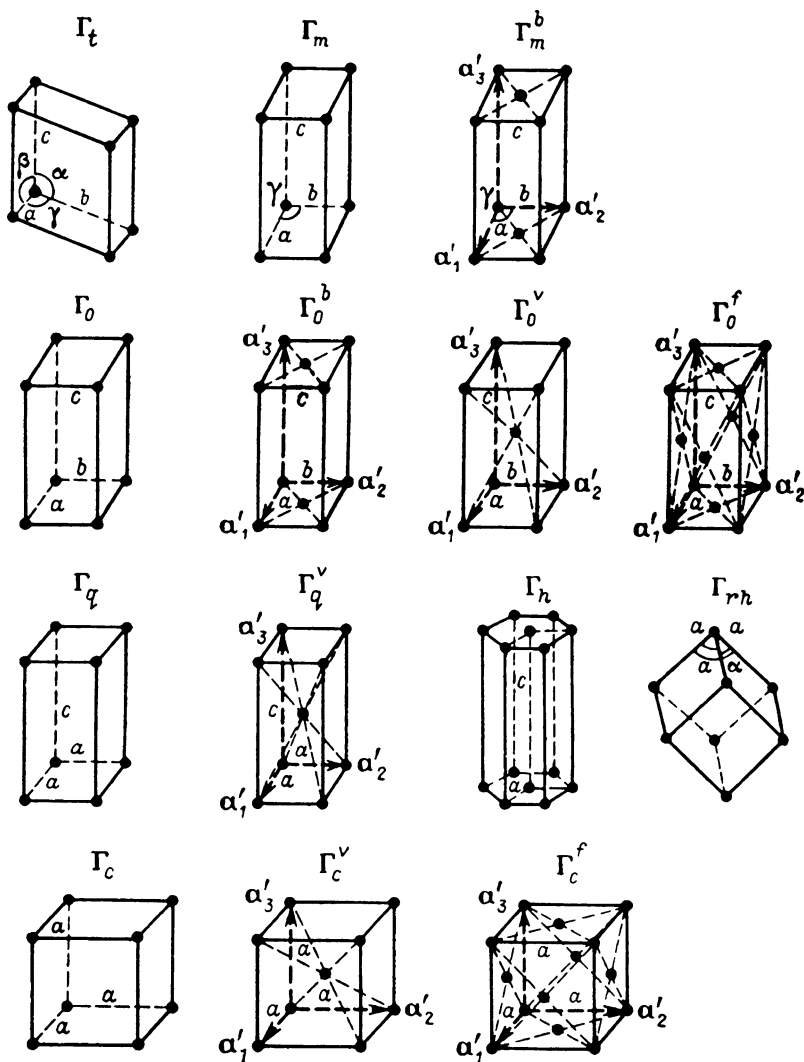


Fig. 2.2 Three-dimensional Bravais lattices

given directly. In the second case, the lengths a and c of the hexagonal unit-cell translation vectors are given: this cell consists of three primitive rhombohedral cells (so-called hexagonal setting for rhombohedral Bravais lattice).

Three *cubic* lattices (simple Γ_c , face-centered Γ_c^f and body-centered Γ_c^v) are defined by one lattice parameter a —the length of conventional cubic cell edge (see Table 2.1 and Fig. 2.2).

The unit cell of a crystal is defined as that volume of space that its translations allow all the space without intervals and superpositions to be covered. The PUC is

Table 2.2 Crystallographic point groups: Schoenflies and International notations

International			International		
Schoenflies	Full	Abbreviated	Schoenflies	Full	Abbreviated
C_n	n	n	D_2	32	32
$C_s(C_{1h})$	m	m	D_4	422	422
$C_i(S_2)$	I	T	D_6	622	622
S_4	4	4	D_{2h}	$2/m\ 2/m\ 2/m$	mmm
S_6	3	3	D_{3h}	$6m2$	$6m2$
C_{2h}	$2/m$	$2/m$	D_{4h}	$4/m\ 2/m\ 2/m$	$4/mmm$
C_{ih}	6	6	D_{6h}	$6/m\ 2/m\ 2/m$	$6/mmm$
C_{4h}	$4/m$	$4/m$	D_{2d}	$42m$	$42m$
C_{6h}	$6/m$	$6/m$	D_{3d}	$32/m$	$3m$
C_{2v}	$2mm$	$2mm$	T	23	23
C_{3v}	$3m$	$3m$	T_h	$2/m3$	$m3$
C_{4v}	$4mm$	$4mm$	T_d	$43m$	$43m$
C_{6v}	$6mm$	$6mm$	O	432	432
D_2	222	222	O_h	$4/m\ 3\ 2/m$	$m3m$

the minimal volume $V_a = \mathbf{a}_1[\mathbf{a}_2 \times \mathbf{a}_3]$ unit cell connected with one Bravais lattice point. Conventional unit cells are defined by two, four, and two lattice points, for the base-, face-, and body-centered lattices, respectively.

The 32 point groups, enumerated in Table 2.2, are known as crystallographic point groups and are given in Schönflies (Sch) notation. The Sch notation is used for molecules. In describing crystal symmetry, the international notation (or Hermann–Mauguin notation) is also of use. In the latter, the point-group notation is determined from the principal symmetry elements: an n fold axis is denoted by the symbol n , a reflection mirror plane by symbol m . The symbols n/m and nm are used for the combinations of an n fold axis with the reflection plane perpendicular to the axis or containing the axis, respectively. Instead of mirror rotation axes, the international system uses inversion axes $\bar{n}$ when a rotation through an angle $2\pi/n$ is followed by the inversion operation. The full international notation of a point group consists of the symbols of group generators. Abbreviated international notations are also used. The Schoenflies and international full and abbreviated notations of crystallographic point groups are given in Table 2.2.

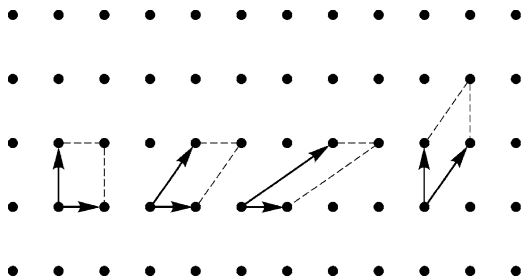
Let us make a linear transformation of PUC translation vectors:

$$\mathbf{A}_j = \sum_{i=1}^3 l_{ji} \mathbf{a}_i, \quad |\det \mathbf{l}| = L \quad (2.8)$$

where the integer coefficients l_{ji} form the matrix $\mathbf{l}$. Vectors $\mathbf{A}_j$ and their integer linear combinations

$$\mathbf{A}_n = \sum_{j=1}^3 n_j \mathbf{A}_j \quad (2.9)$$

Fig. 2.3 Different primitive unit cell choices



define for $L > 1$ new, “rare” Bravais lattice for which it is possible to consider various unit cells also. The primitive cell of a new lattice with volume $V_A = L \times V_a$ will be the so-called large unit cell (supercell), in relation to an initial primitive unit cell. At $L = 1$ transformation, (2.8) means transferring to other vectors of the basic translations, to another under the form, but not on the volume primitive cell (see Fig. 2.3).

The crystallographic(conventional) unit cell is defined as the minimal volume unit cell in the form of a parallelepiped constructed on vectors of translations and possessing the point symmetry of the lattice. For simple lattices P of all syngonies, except for hexagonal (H), the vectors of the basic translations can be chosen in such a manner that the primitive cell constructed on them is crystallographic. For the centered lattices, the crystallographic unit cells consist of 2, 4, and 2 primitive cells for base-, face-, and body-centered lattices, respectively (Fig. 2.2). In the description of symmetry of a trigonal crystal, both rhombohedral and hexagonal cells are used. The latter is defined by transformation (2.8) with a matrix

$$l = \begin{pmatrix} 2 & 1 & 0 \\ -1 & 1 & 0 \\ 1 & 1 & 1 \end{pmatrix} \quad (2.10)$$

and $L = 3$. As $L = 3$ for this matrix the hexagonal unit cell contains 3 rhombohedral unit cells.

2.2 Space Groups

2.2.1 Space Groups of Bravais Lattices. Symmorphic and Nonsymmorphic Space Groups

As considered in the previous section, Bravais lattices define the group T of lattice translations. The general symmetry transformation of a Bravais lattice “empty” lattice) can be written in the form $t_a R$. Operations R transform any translation

vector $\mathbf{a}$ to another translation vector $R\mathbf{a}$ and form point group F^0 (holohedric point group). The combined operation $t_a R$ transforms the point of space with radius-vector $\mathbf{r}$ to an equivalent point $\mathbf{r}' = R\mathbf{r} + \mathbf{a}$. The identity element of the Bravais lattice symmetry group is $t_0 E$. The multiplication law for operations $t_a R$ is

$$t_{a_1} R_1 t_{a_2} R_2 \mathbf{r} = R_1 R_2 \mathbf{r} + \mathbf{a}_1 + R_1 \mathbf{a}_2 = t_{\mathbf{a}_1 + R_1 \mathbf{a}_2} R_1 R_2 \mathbf{r} \quad (2.11)$$

so that

$$(t_a R)^{-1} \mathbf{r} = R^{-1} \mathbf{r} - R^{-1} \mathbf{a} = t_{-R^{-1} \mathbf{a}} R^{-1} \mathbf{r} \quad (2.12)$$

The operations t_a and R do not commute. Indeed

$$t_a R \mathbf{r} = R \mathbf{r} + \mathbf{a}; \quad R t_a \mathbf{r} = R(\mathbf{r} + \mathbf{a}) = R \mathbf{r} + t_{R\mathbf{a}} = t_{R\mathbf{a}} R \mathbf{r} \quad (2.13)$$

so that

$$t_a R = R t_{R^{-1} \mathbf{a}} \quad (2.14)$$

Operations $t_a R$ form the space group G^0 of an “empty” Bravais lattice. As lattice translations (also called proper translations) t_a and point-symmetry operations R do not commute, the space groups $G^0 = T \wedge F^0$ are a semidirect product of the translation and point groups of lattice symmetry. The point-symmetry operations R form subgroup F^0 of space group G^0 (such space groups are termed symmorphic space groups). The group T of pure translations forms an invariant subgroup of G^0 . As $t_a^{-1} = t_{-\mathbf{a}}$, we have $(t_a R)^{-1} t_{a'} t_a R = (t_a R)^{-1} t_{\mathbf{a} + \mathbf{a}'} R = t_{R\mathbf{a}'}$.

The group of translations T is a subgroup of the full group symmetry G that also contains operations of point group F and their combinations with translations. Groups of symmetry of crystals are called space groups. The space groups do not necessarily contain translations in three-dimensional space. In two-periodic space groups, translations only in a plane appear (such groups are used, e.g., in the crystalline surface modeling: see Chap. 11). One-periodic space-group elements include translations only along an axis (e.g., symmetry groups of polymers). There is difference between two-periodic and plane groups: in the former, the symmetry operations are transformations in a whole three-dimensional space, in the latter—only in plane (there are known 80 two-periodic groups and 17 plane groups [19]).

Any symmetry operation g of a crystal with space group G can be written in the form of $g_i = t_{\mathbf{v}_i + \mathbf{a}} R_i$ where $\mathbf{v}_i$ is the so-called improper (fractional) translation, depending on element R_i of a point group of a crystal and satisfying the requirements described below. The operation g_i transforms the point of space with radius-vector $\mathbf{r}$ to an equivalent point $\mathbf{r}' = g_i \mathbf{r} = R_i \mathbf{r} + \mathbf{v}_i$. The operations t_a are elements of the group of translations T —translations on the corresponding vector of the Bravais lattice.

In crystals, unlike molecules, together with rotations through axes of symmetry and reflections in planes, there exist rotations through screw axes (rotation followed by translation along a rotation axis on a part of a vector of translation) and reflections in planes with partial translation in a plane (such planes are termed glide planes).

Translation along a screw axis of symmetry cannot be arbitrary and depends on the order of this axis. Let the order of an axis be equal to n (n rotations through axis are equivalent to an identity operation). Thus, n translations along an axis should give a vector of translation of a lattice, *that is*, an element of group T that forms a subgroup of a space group of a crystal. Otherwise, rotation through a screw axis will not be an operation of symmetry. For example, rotation through an axis of the fourth order can be accompanied by translation along this axis on a quarter or half of the vector of translation. A similar requirement is imposed on the operation of sliding reflection: two sequential reflections in a glide plane should be equivalent to translation on a vector of a lattice. By definition, any symmetry operation g of a space group transforms any atom of a crystal to equivalent atom. The equivalent atoms are always the atoms of the same chemical identity, but the latter can be nonequivalent (see Chap. 3). Therefore, fractional (improper) translations can appear only in those crystals that contain several equivalent atoms in the primitive unit cell. The presence of identical atoms in a primitive cell—a condition necessary but insufficient for the occurrence of fractional translations in the space-group elements. As an example, we consider in Sect. 2.3 the perovskite CaTiO_3 structure with three equivalent oxygen atoms in a primitive unit cell and symmorphic space group O_h^1 .

The set of fractional translations $\mathbf{v}$ in the space-group elements $g = t_{\mathbf{v}}R$ depends on the choice of origin (with respect to which the space-group elements are written) and on the labeling of axes (choice of setting) [19].

By definition, the symmorphic space groups contain, together with each element $t_a R$, the elements R and t_a of the point group F and translation group T , respectively. This means that for a symmorphic space group, the origin of the coordinate system may be chosen in such a way that the local (site-) symmetry group of origin coincides with the point group of the crystal F . This means that all fractional translations $\mathbf{v}$ are zero. Such a choice of origin is accepted for symmorphic space groups in the International Tables [19]. For nonsymmorphic space groups, some fractional translations will be nonzero for any choice of origin.

In the next subsection, we discuss 73 symmorphic and 157 nonsymmorphic space groups.

2.2.2 Three-Periodic Space Groups

The full information on space groups is given in the International Tables for Crystallography [19] and presented on a site [16]. The knowledge of general principles of the space-group designations is necessary to use the crystal-structure databases correctly.

Table 2.3 gives the list of 230 three-periodic space groups (two-periodic space groups are considered in Chap. 11). The point-group F symbols are underlined for the space groups that appear as the first ones in the list of a given crystal class.

The seven holohedric point groups F^0 and all their subgroups form 32 crystallographic point groups (32 crystalline classes). By combining these 32 point groups with the translation groups of 14 Bravais lattices, 73 symmorphic space groups are

Table 2.3 Two hundred and thirty three-periodic space groups

N_G	G	IG	N_G	G	IG	N_G	G	IG
Triclinic								
1	C_1^1	$P\bar{1}$	2	C_i^1	$P\bar{1}$			
Monoclinic								
3	C_2^1	$P2$	4	C_2^2	$P2_1$	5	C_2^3	$C2$
6	C_s^1	Pm	7	C_s^2	Pc	8	C_s^3	Cm
9	C_s^4	Cc	10	C_{2h}^1	$P2/m$	11	C_{2h}^2	$P2_1/m$
12	C_{2h}^3	$C2/m$	13	C_{2h}^4	$P2/c$	14	C_{2h}^5	$P2_1/c$
15	C_{2h}^6	$C2/c$						
Orthorhombic								
16	D_2^1	$P222$	17	D_2^2	$P222_1$	18	D_2^3	$P2_12_12$
19	D_2^4	$P2_12_12_1$	20	D_2^5	$C222_1$	21	D_2^6	$C222$
22	D_2^7	$F222$	23	D_2^8	$I222$	24	D_2^9	$I2_12_12_1$
25	C_{2v}^1	$Pmm2$	26	C_{2v}^2	$Pmc2_1$	27	C_{2v}^3	$Pcc2$
28	C_{2v}^4	$Pma2$	29	C_{2v}^5	$Pca2_1$	30	C_{2v}^6	$Pnc2$
31	C_{2v}^7	$Pmn2_1$	32	C_{2v}^8	$Pba2$	33	C_{2v}^9	$Pna2_1$
34	C_{2v}^{10}	$Pnn2$	35	C_{2v}^{11}	$Cmm2$	36	C_{2v}^{12}	$Cmc2_1$
37	C_{2v}^{13}	$Ccc2$	38	C_{2v}^{14}	$Amm2$	39	C_{2v}^{15}	$Abm2$
40	C_{2v}^{16}	$Ama2$	41	C_{2v}^{17}	$Aba2$	42	C_{2v}^{18}	$Fmm2$
43	C_{2v}^{19}	$Fdd2$	44	C_{2v}^{20}	$Imm2$	45	C_{2v}^{21}	$Iba2$
46	C_{2v}^{22}	$Ima2$	47	D_{2h}^1	$Pmmm$	48	D_{2h}^2	$Pnnn$
49	D_{2h}^3	$Pccm$	50	D_{2h}^4	$Pban$	51	D_{2h}^5	$Pmma$
52	D_{2h}^6	$Pnna$	53	D_{2h}^7	$Pmna$	54	D_{2h}^8	$Pcca$
55	D_{2h}^9	$Pbam$	56	D_{2h}^{10}	$Pccn$	57	D_{2h}^{11}	$Pbcm$
58	D_{2h}^{12}	$Pnnm$	59	D_{2h}^{13}	$Pmnn$	60	D_{2h}^{14}	$Pbcn$
61	D_{2h}^{15}	$Pbca$	62	D_{2h}^{16}	$Pnma$	63	D_{2h}^{17}	$Cmcm$
64	D_{2h}^{18}	$Cmca$	65	D_{2h}^{19}	$Cmmm$	66	D_{2h}^{20}	$Cccm$
67	D_{2h}^{21}	$Cmma$	68	D_{2h}^{22}	$Ccca$	69	D_{2h}^{23}	$Fmmm$
70	D_{2h}^{24}	$Fddd$	71	D_{2h}^{25}	$Immm$	72	D_{2h}^{26}	$Ibam$
73	D_{2h}^{27}	$Ibca$	74	D_{2h}^{28}	$Imma$			
Tetragonal								
75	C_4^1	$P4$	76	C_4^2	$P4_1$	77	C_4^3	$P4_2$
78	C_4^4	$P4_3$	79	C_4^5	$I4$	80	C_4^6	$I4_1$
81	S_4^1	$P\bar{4}$	82	S_4^2	$I\bar{4}$	83	C_{4h}^1	$P4/m$
84	C_{4h}^2	$P4_2/m$	85	C_{4h}^3	$P4/n$	86	C_{4h}^4	$P4_2/n$
87	C_{4h}^5	$I\bar{4}/m$	88	C_{4h}^6	$I4_1/a$	89	D_4^1	$P\bar{4}22$
90	D_4^2	$P4_212$	91	D_4^3	$P4_122$	92	D_4^4	$P4_12_12$
Tetragonal								
93	D_4^5	$P4_222$	94	D_4^6	$P4_22_12$	95	D_4^7	$P4_322$
96	D_4^8	$P4_32_12$	97	D_4^9	$I422$	98	D_4^{10}	$I4_122$
99	C_{4v}^1	$P\bar{4}mm$	100	C_{4v}^2	$P4bm$	101	C_{4v}^3	$P4_2cm$
102	C_{4v}^4	$P4_2nm$	103	C_{4v}^5	$P4cc$	104	C_{4v}^6	$P4nc$
105	C_{4v}^7	$P4_2mc$	106	C_{4v}^8	$P4_2bc$	107	C_{4v}^9	$I4mm$
108	C_{4v}^{10}	$I4cm$	109	C_{4v}^{11}	$I4_1md$	110	C_{4v}^{12}	$I4_1cd$
111	D_{2d}^1	$P\bar{4}2m$	112	D_{2d}^2	$P\bar{4}2c$	113	D_{2d}^3	$P\bar{4}2_1m$

(continued)

Table 2.3 (continued)

N_G	G	IG	N_G	G	IG	N_G	G	IG
114	D_{2d}^4	$P\bar{4}2_1c$	115	D_{2d}^5	$P\bar{4}m2$	116	D_{2d}^6	$P\bar{4}c2$
117	D_{2d}^7	$P\bar{4}b2$	118	D_{2d}^8	$P\bar{4}n2$	119	D_{2d}^9	$I\bar{4}m2$
120	D_{2d}^{10}	$I\bar{4}c2$	121	D_{2d}^{11}	$I\bar{4}2m$	122	D_{2d}^{12}	$I\bar{4}2d$
123	D_{4h}^1	$P4/mmm$	124	D_{4h}^2	$P4/mcc$	125	D_{4h}^3	$P4/nbm$
126	D_{4h}^4	$P4/nnc$	127	D_{4h}^5	$P4/mbm$	128	D_{4h}^6	$P4/mnc$
129	D_{4h}^7	$P4/nmm$	130	D_{4h}^8	$P4/ncc$	131	D_{4h}^9	$P4_2/mmc$
132	D_{4h}^{10}	$P4_2/mcm$	133	D_{4h}^{11}	$P4_2/nbc$	134	D_{4h}^{12}	$P4_2/nnm$
135	D_{4h}^{13}	$P4_2/mbc$	136	D_{4h}^{14}	$P4_2/mnm$	137	D_{4h}^{15}	$P4_2/nmc$
138	D_{4h}^{16}	$P4_2/ncm$	139	D_{4h}^{17}	$I4/mmm$	140	D_{4h}^{18}	$I4/mcm$
141	D_{4h}^{19}	$I4_1/amd$	142	D_{4h}^{20}	$I4_1/acd$			
Rhombohedral								
143	C_3^1	$P\bar{3}$	144	C_3^2	$P3_1$	145	C_3^3	$P3_2$
146	C_3^4	$R\bar{3}$	147	C_{3i}^1	$P\bar{3}$	148	C_{3i}^2	$R\bar{3}$
149	D_3^1	$P\bar{3}12$	150	D_3^2	$P321$	151	D_3^3	$P3_112$
152	D_3^4	$P3_121$	153	D_3^5	$P3_212$	154	D_3^6	$P3_221$
155	D_3^7	$R32$	156	C_{3v}^1	$P\bar{3}m1$	157	C_{3v}^2	$P31m$
158	C_{3v}^3	$P3c1$	159	C_{3v}^4	$P31c$	160	C_{3v}^5	$R3m$
161	C_{3v}^6	$R3c$	162	D_{3d}^1	$P\bar{3}1m$	163	D_{3d}^2	$P\bar{3}1c$
164	D_{3d}^3	$P\bar{3}m1$	165	D_{3d}^4	$P\bar{3}c1$	166	D_{3d}^5	$R\bar{3}m$
167	D_{3d}^6	$R\bar{3}c$						
Hexagonal								
168	C_6^1	$P\bar{6}$	169	C_6^2	$P6_1$	170	C_6^3	$P6_5$
171	C_6^4	$P6_2$	172	C_6^5	$P6_4$	173	C_6^6	$P6_3$
174	C_{3h}^1	$P\bar{6}$	175	C_{6h}^1	$P6/m$	176	C_{6h}^2	$P6_3/m$
177	D_6^1	$P\bar{6}62$	178	D_6^2	$P6_122$	179	D_6^3	$P6_522$
180	D_6^4	$P6_222$	181	D_6^5	$P6_422$	182	D_6^6	$P6_322$
183	C_{6v}^1	$P6mm$	184	C_{6v}^2	$P6cc$	185	C_{6v}^3	$P6_3cm$
186	C_{6v}^4	$P6_3mc$	187	D_{3h}^1	$P\bar{6}m2$	188	D_{3h}^2	$P\bar{6}c2$
189	D_{3h}^3	$P\bar{6}2m$	190	D_{3h}^4	$P\bar{6}2c$	191	D_{6h}^1	$P6/mmm$
192	D_{6h}^2	$P6/mcc$	193	D_{6h}^3	$P6_3/mcm$	194	D_{6h}^4	$P6_3/mmc$
Cubic								
195	T^1	$P\bar{2}3$	196	T^2	$F23$	197	T^3	$I23$
198	T^4	$P2_13$	199	T^5	$I2_13$	200	T_h^1	$Pm\bar{3}$
201	T_h^2	$Pn\bar{3}$	202	T_h^3	$Fm\bar{3}$	203	T_h^4	$Fd\bar{3}$
204	T_h^5	$Im\bar{3}$	205	T_h^6	$Pa\bar{3}$	206	T_h^7	$Ia\bar{3}$
207	O^1	$P\bar{4}32$	208	O^2	$P4_232$	209	O^3	$F432$
210	O^4	$F4_132$	211	O^5	$I432$	212	O^6	$P4_332$
213	O^7	$P4_132$	214	O^8	$I4_132$	215	T_d^1	$P\bar{4}3m$
216	T_d^2	$F\bar{4}3m$	217	T_d^3	$I\bar{4}3m$	218	T_d^4	$P\bar{4}3n$
219	T_d^5	$F\bar{4}3c$	220	T_d^6	$I\bar{4}3d$	221	O_h^1	$Pm\bar{3}m$
222	O_h^2	$Pn\bar{3}n$	223	O_h^3	$Pm\bar{3}n$	224	O_h^4	$Pn\bar{3}m$
225	O_h^5	$Fm\bar{3}m$	226	O_h^6	$Fm\bar{3}c$	227	O_h^7	$Fd\bar{3}m$
228	O_h^8	$Fd\bar{3}c$	229	O_h^9	$Im\bar{3}m$	230	O_h^{10}	$Ia\bar{3}d$

obtained, including 14 space groups of the symmetry of empty Bravais lattices (see Table 2.3). The remaining 157 space groups include point-symmetry operations with improper (partial) translations, *that is*, rotations through screw axes and reflections in glide planes.

There are three systems of designations of space groups. First, all groups are numbered from 1 up to 230 in order of increasing point symmetry of the corresponding Bravais lattice (syngonies from triclinic to cubic). For fixed syngony, the ordering is made over Bravais lattice types and for the fixed Bravais lattice type—over crystal classes (point group F) beginning from the symmorphic space group. In this list, the space groups of “empty” lattices appear as the first ones for fixed type of the lattice. Secondly, the more informative Schönflies symbol is used for space groups. This contains the Schönflies symbol of point group F of a crystal class and the upper numerical index distinguishing space groups within the limits of one crystal class.

Thirdly, the most detailed information on a space group is contained in so-called international designations. In these there are both a symbol of the Bravais lattice type and a symbol of a crystal class with the indication of the elements of symmetry (axes and planes). For a designation of types of Bravais lattices, the following symbols (see Table 2.3) are used: P —simple (or primitive); A , B , C —one face (base-) centered; F —face centered; and I —body centered. For hexagonal and trigonal (rhombohedral) lattices, symbols H and R are accepted. The letter is followed by a set of characters indicating the symmetry elements. These sets are organized in the following way.

There exist only two triclinic space groups (1, 2) with symbols $P1$ (no point-symmetry operations) and $P\bar{1}$ (the inversion operation appears, and this is the symmetry group of triclinic Bravais lattice). For monoclinic space groups (3–15), one symbol is needed that gives the nature of the twofold axis (rotation axis 2 or screw axis 2_1) or reflection plane (mirror plane m or glide plane c). Two settings are used for monoclinic space groups: y-axis unique or, used in Table 2.3, z-axis unique. Primitive and base-centered (z-axis unique) monoclinic Bravais lattices symmetry groups are $P2/m$ (10) and $C2/m$ (11), respectively.

The symbols of orthorhombic space groups (16–74) contain the three sets. For symmorphic groups as a symbol of a crystal class, the international designation of point groups corresponding to it serves. In Table 2.3, conformity of Schönflies’s symbols (applied for molecules) and international symbols for point groups of symmetry of crystals is given, for example, $N225$, O_h^5 , and $Fm\bar{3}m$ —three symbols of the same space groups of symmetry of a crystal with NaCl structure. For nonsymmorphic groups in a symbol of the point group, it is underlined also, which axes are screw and which planes are planes of the sliding reflections. For example, for the group of symmetry of rutile structure, it is possible to use designations $N136$, D_{4h}^{14} , or $P4_2/mnm$, where the symbol 4_2 means that an axis of the fourth order is a screw axis, with translation on half a period along this axis on rotation by angle $\pi/2$, and a symbol n means that two of the four vertical planes are planes of sliding reflection. A more detailed explanation of the principles of international

designations can be found in [19]. In Table 2.3 is given the list of 230 space groups with the indication of all three mentioned designations for each of them.

2.2.3 Site Symmetry in Crystals. Wyckoff Positions

To characterize a space group G , an analytical description may be employed, which states for a space group the coordinates of all points that are equivalent to a chosen point $\mathbf{q}$ with coordinates (xyz) . An analytical description of all 230 space groups is given in the International Tables for Crystallography [19] and is based on the fact that for a given space group G , all points of a three-dimensional space are subdivided into sets of symmetrically equivalent points called crystallographic orbits.

All the points of a given crystallographic orbit may be obtained from one (arbitrary) crystallographic orbit point $\mathbf{q}$ (generating point) by applying to the latter all the operations of space group G . Due to the infinite number of translations (in the model of an infinite crystal), there is an infinite number of points in each space group crystallographic orbit. Any one of the crystallographic orbit points may represent the whole crystallographic orbit, *that is*, may be a generating point $\mathbf{q}$ of the crystallographic orbit.

All symmetry operations $t_{\mathbf{v}+\mathbf{a}}R_i = (R_i|\mathbf{v}_i + \mathbf{a})$, $i = 1, 2, \dots, n_q$ of a space group G that satisfy the condition $t_{\mathbf{v}+\mathbf{a}}R\mathbf{q} = \mathbf{q}$ form a finite site-symmetry group G_q of $\mathbf{q}$ with respect to G . The site-symmetry group G_q is isomorphic to one of the 32 crystallographic point groups. If the origin of the space group is at the position $\mathbf{q}$, the elements of the site-symmetry group G_q will be of the form t_0R .

The site-symmetry groups G_j of different points $\mathbf{q}_j$ of the same crystallographic orbit are conjugate groups of $G_1 = G_q$, *that is*, the site-symmetry groups G_1 and G_j of points $\mathbf{q}_1 = \mathbf{q}$ and $\mathbf{q}_j$ of the same orbit are related by $g_j G_1 g_j^{-1} = G_j$ ($g_j \in G$, $g_j \notin G_j$, $g_j \mathbf{q}_1 = \mathbf{q}_j$). For a point $\mathbf{q}$ at a general position, the site-symmetry group G_q consists of only the identity operation $t_0E = (E|\mathbf{0})$; the site-symmetry group of a point at a special position includes at least one other symmetry operation in addition to the identity operation.

An infinite number of crystallographic orbits for a given space group G can be subdivided into sets of so-called Wyckoff positions of G . All the crystallographic orbits that have the same (not only isomorphic but the same) site-symmetry group belong to the same Wyckoff position. If the coordinates of the generating point of a crystallographic orbit do not contain free parameters, the corresponding Wyckoff position consists of only one crystallographic orbit; in other cases, an infinite number of crystallographic orbits belong to the same Wyckoff position with variable parameters.

The different Wyckoff positions are labeled by small Roman letters. The maximum number of different Wyckoff positions of a space group is 27 (in the group $D_{2h}^1 - Pmmm$). The various possible sets of Wyckoff positions for all the space groups are given in the International Tables for Crystallography [19] and reproduced on an Internet site [16]. As an example, Table 2.4 lists those for the

Table 2.4 Wyckoff positions of space group 136 ($P4_2/mnm$)^a

Multipl.	Wyck. letter	Site symm.	Coordinates
16	k	1	$(x, y, z)(-x, -y, z)(-y + 1/2, x + 1/2, z + 1/2)$ $(y + 1/2, -x + 1/2, z + 1/2)(-x + 1/2, y + 1/2, -z + 1/2)$ $(x + 1/2, -y + 1/2, -z + 1/2)(y, x, -z)(-y, -x, -z)$ $(-x, -y, -z)(x, y, -z)(y + 1/2, -x + 1/2, -z + 1/2)$ $(-y + 1/2, x + 1/2, -z + 1/2)(x + 1/2, -y + 1/2, z + 1/2)$ $(-x + 1/2, y + 1/2, z + 1/2)(-y, -x, z)(y, x, z)$
8	j	..m	$(x, x, z)(-x, -x, z)(-x + 1/2, x + 1/2, z + 1/2)$ $(x + 1/2, -x + 1/2, z + 1/2)(-x + 1/2, x + 1/2, -z + 1/2)$ $(x + 1/2, -x + 1/2, -z + 1/2)(x, x, -z)(-x, -x, -z)$
8	i	m..	$(x, y, 0)(-x, -y, 0)(-y + 1/2, x + 1/2, 1/2)$ $(y + 1/2, -x + 1/2, 1/2)(-x + 1/2, y + 1/2, 1/2)$ $(x + 1/2, -y + 1/2, 1/2)(y, x, 0)(-y, -x, 0)$
8	h	2..	$(0, 1/2, z)(0, 1/2, z + 1/2)(1/2, 0, -z + 1/2)$ $(1/2, 0, -z)(0, 1/2, -z)(0, 1/2, -z + 1/2)$ $(1/2, 0, z + 1/2)(1/2, 0, z)$
4	g	m.2 m	$(x, -x, 0)(-x, x, 0)(x + 1/2, x + 1/2, 1/2)$ $(-x + 1/2, -x + 1/2, 1/2)$
4	f	2.m m	$(x, x, 0)(-x, -x, 0)(-x + 1/2, x + 1/2, 1/2)$ $(x + 1/2, -x + 1/2, 1/2)$
4	e	2.m m	$(0, 0, z)(1/2, 1/2, z + 1/2)(1/2, 1/2, -z + 1/2)$ $(0, 0, -z)$
4	d	$\bar{4}..$	$(0, 1/2, 1/4)(0, 1/2, 3/4)(1/2, 0, 1/4)$ $(1/2, 0, 3/4)$
4	c	2/m..	$(0, 1/2, 0)(0, 1/2, 1/2)(1/2, 0, 1/2)(1/2, 0, 0)$
2	b	m.m m	$(0, 0, 1/2)(1/2, 1/2, 0)$
2	a	m.m m	$(0, 0, 0)(1/2, 1/2, 1/2)$

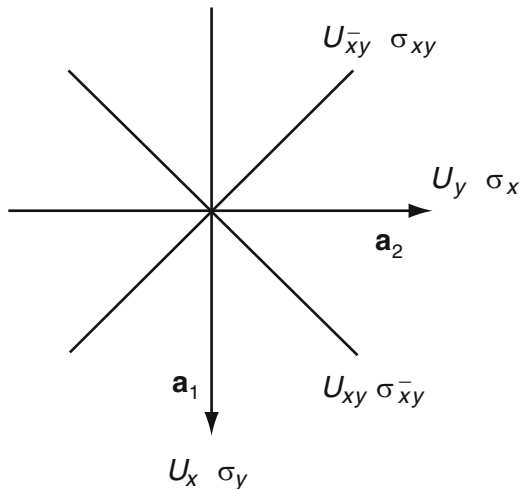
^a Equivalent sets of Wyckoff positions.

(ab)(c)(d)(e)(fg)(h)(i)(j)(k)

space group $D_{4h}^{14}(P4_2/m2_l/n2/m)$, the symmetry group of a rutile structure (see Sect. 2.3.3).

For this group, there are 11 different Wyckoff positions denoted by letters from a to k. The number of crystallographic orbit points in the primitive unit cell (multiplicity) equals n_F/n_q where $n_F = 16$ is the order of the point group D_{4h} and n_q is the order of the site symmetry group G_q . The number of points in a Wyckoff position and their coordinates are given in the International Tables with respect to the conventional unit cell of the lattice (for the space group D_{4h}^{14} with a simple Bravais lattice, the conventional unit cell coincides with the primitive unit cell). Use of the

Fig. 2.4 Orientation of the symmetry elements with respect to the tetragonal lattice translations



Wyckoff general position $k(xyz)$ points allows one to determine the appropriate Seitz space-group symbols for the coset representatives in the decomposition

$$G = \sum_{i=1}^{n_F} (R_i | v_i) T = \sum_{i=1}^{n_F} t_{v_i} R_i T \quad (2.15)$$

of space group G with respect to the translation group T . In Table 2.4 these symbols are written under the coordinates of the points obtained from the point $\mathbf{r}(x, y, z)$ by performing the space-group operation $t_v R$. The orientation of the symmetry elements with respect to the tetragonal lattice translation vectors $\mathbf{a}_1(a, 0, 0)$, $\mathbf{a}_2(0, a, 0)$, and $\mathbf{a}_3(0, 0, c)$ is shown in Fig. 2.4. In the point group D_{4h} , there are four rotations around twofold axes ($U_x, U_y, U_{xy}, U_{\bar{x}y}$) and four rotations (including the identity operation) around the main fourfold z -axis ($E, C_{4z}, C_{4z}^2 = C_{2z}, C_{4z}^3 = C_{4z}^{-1}$).

The remaining 8 symmetry operations are all products of inversion I with rotations: I , reflections $\sigma_x, \sigma_y, \sigma_{xy}, \sigma_{\bar{x}y}, \sigma_z$ in the planes perpendicular to the corresponding twofold axes and z -axis, mirror rotations S_{4z}^{-1}, S_{4z} . It is seen from Table 2.4 that the elements of the point group $D_{2h}(E, C_{2z}, U_{xy}, U_{\bar{x}y}, I, \sigma_z, \sigma_{xy}, \sigma_{\bar{x}y})$ appear in the cosets decomposition (2.15) without fractional translations. These elements form the site symmetry group of the coordinate system origin placed at the point of Wyckoff position $a(0, 0, 0)$. The second point of this position $(1/2, 1/2, 1/2)$ is obtained from the first one by application of any symmetry operation from these eight ($C_{4z}, C_{4z}^{-1}, S_{4z}, S_{4z}^{-1}, U_x, U_y, \sigma_x, \sigma_y$) that come into the coset representatives in (2.15) with fractional translation $\mathbf{v} = (1/2, 1/2, 1/2)$. We therefore write the space group D_{4h}^{14} (for the case when the Wyckoff position a is taken as the origin) as

$$D_{4h}^{14} = \sum_{R \in D_{2h}} \left[(R|0)T + \left(U_x \left| \frac{1}{2} \frac{1}{2} \frac{1}{2} \right. \right) (R|0)T \right] \quad (2.16)$$

Considering the full international symbol $P4_2/m2_1/n2/m$ of the space group D_{4h}^{14} , we see that the coset representatives in the decomposition of (2.15) with respect to the translation group T correspond to this symbol. Indeed, in our example of a tetragonal lattice, the three positions in this symbol correspond to the symmetry directions $[001]$; $[100]$, $[010]$; and $[1\bar{1}0]$, $[110]$, respectively. Rotation through the angle $\pi/2$ about the z -axis is followed by translation along this axis by one-half of the translation vector $\mathbf{a}_3$ as is seen from the symbol for the element $(C_{4z}|l/2, 1/2, 1/2)$. The notations 2_l and 2 for twofold x - and xy -rotation axes agree with the fourfold symbols for $(U_x|\frac{1}{2}\frac{1}{2}\frac{1}{2})$ and $(U_{xy}|000)$. Finally, the notations m , n , m for the reflection planes perpendicular to the corresponding symmetry directions in the international symbol for the space group agree with the Seitz symbols $(\sigma_z|000)$, $(\sigma_x|\frac{1}{2}\frac{1}{2}\frac{1}{2})$, and $(\sigma_{xy}|000)$, respectively. The space group D_{4h}^{14} may also be described by its six generators: three primitive translations $t_{a_i} = (E|\mathbf{a}_i)$ ($i = 1, 2, 3$) of the simple tetragonal lattice and three generating elements $(C_{4z}|l/2, 1/2, 1/2)$, $(U_x|l/2, 1/2, 1/2)$, $(I|0, 0, 0)$.

The coordinates of Wyckoff positions a , b , c , d do not contain free parameters (Table 2.4); those of e , f , g , h positions contain one free parameter; the coordinates of the positions i and j contain two free parameters. This means that an infinite number of Wyckoff sets e – f exists in the crystal but the sets a , b , c , d consist of only one crystallographic orbit. Pairs of Wyckoff positions a – b , f – g , and i – j have isomorphic site symmetry groups (D_{2h} , C_{2v} , and C_s , respectively). As is seen from the table, pairs of points a – b and f – g not only have isomorphic but also equivalent Wyckoff positions. The equivalent sites have the same point-group symmetry and the same orientations of symmetry elements with respect to the lattice. The equivalent sets of Wyckoff positions for all the space groups can be found on the Internet site [16]. This information will be used in the next section for the description of different crystal lattice structures. This means that if equivalent points are occupied by atoms in the crystal lattice, there are possible equivalent descriptions of this structure. For example, rutile TiO_2 structure with two formula units in the primitive cell can be given in two equivalent descriptions: $\text{Ti}(2a)\text{O}(4f)$ or $\text{Ti}(2b)\text{O}(4g)$. For NbOCl_3 structure ($Z = 4$) with the same space group, two equivalent descriptions can be given: $\text{Nb}(4f)\text{O}(4g)\text{Cl}(4g)\text{Cl}(8i)$ and $\text{Nb}(4g)\text{O}(4f)\text{Cl}(4f)\text{Cl}(8i)$. In this case, the $\text{Cl}(8i)$ position is the same but $\text{Cl}(4f)$ and $\text{Cl}(4g)$ positions interchange.

The difference between oriented site-symmetry groups of different Wyckoff positions is due to different orientations of the elements of the site-symmetry group G_q with respect to the lattice. The difference arises when similar symmetry elements (reflections in planes and rotations about twofold axes of symmetry) occur in more than one class of elements of the point group F . Only 11 site groups [$C_2(2)$, $C_s(m)$, $C_{2h}(2/m)$, $C_{2v}(2mm)$, $C_{3v}(3mm)$, $D_2(222)$, $D_3(322)$, $D_{2d}(42m)$, $D_{3d}(32m)$, $D_{2h}(mmm)$, and $D_{3d}(62m)$] can have different orientations with respect to the Bravais lattice. Oriented site-symmetry symbols show how the symmetry elements at a site are related to the symmetry elements of a space group. The site-symmetry symbols display the same sequence of symmetry directions as the space-group international symbol. Sets of equivalent symmetry directions that do not contribute

any element to the site-symmetry group G_q are represented by a dot. In our example of the space group D_{4h}^{14} , the site-symmetry groups G_a, G_b do not contain reflection in the planes σ_x, σ_y (the dot is at the second position) and the site group $G_e = 2.m.m$ does not contain reflection in the plane σ_z (a dot is at the first position, Table 2.3).

In the next section, we consider 15 types of crystal structures belonging to different space groups. As will be seen, the different crystal structures can be considered as one or another means of the distribution of the atoms between the Wyckoff positions of the corresponding space group.

2.3 Crystalline Structures

2.3.1 *Crystal-Structure Types: Structure Information for Computer Codes*

The *Bravais lattice* is an infinite set of points generated by three nonparallel basic translation vectors, such that each point is identical in itself and its surroundings; see Sect. 2.1.2. With each Bravais lattice, point may be associated a number of atoms (so-called basis). If atomic coordinates relative to the lattice point are given, together with the lengths and directions of the lattice vectors chosen to define the axes of reference, the complete structure (crystal lattice) is defined. The Internet page <http://cst-www.nrl.navy.mil/lattice/> currently contains links to about 300 structures in more than 90 of the 230 space groups. A graphical representation as well as useful information about these crystal lattices can be obtained. Other sources of information can be found at various sites linked with <http://cst-www.nrl.navy.mil/lattice/others.html>. The crystal-structure type is specified when one states which sets of Wyckoff positions for the corresponding space group are occupied by atoms. To distinguish different structures of the same type, one needs the numerical values of lattice parameters and additional data if Wyckoff positions with free parameters in the coordinates are occupied. When describing the crystal-structure type, one also gives the value of Z (the number of formula units in the conventional unit cell). This information is, in principle, not necessary as Z is defined by the chemical formula of the compound and the multiplicity of Wyckoff positions in the unit cell occupied by atoms. It is also necessary to take into account that the primitive unit cell of any crystal contains half the number of atoms in a body-centered cell, one-quarter of the number in a face-centered cell, and half the number in an A, B , or C base-centered cell. Trigonal cells contain one-third the number of atoms in the corresponding hexagonal cell. The Wyckoff-site description of a crystal-structure type is also origin dependent (see Sect. 2.2.3). It was shown that equivalent alternatives often arise if two or more sets of sites are physically equivalent (see Sect. 2.2.3). The crystal lattice structure types can be indexed in different ways (<http://cst-www.nrl.navy.mil/lattice/>). In *Strukturbericht* designation, symbols A and B are used for monoatomic and diatomic (with equal numbers of atoms of each type) crystal

types, symbols C and D —for AB_2 , and A_nB_m compounds, respectively. Symbols $E, F, G, \dots, K$ specify more complex compounds, symbols L, O , and S specify alloys, organic compounds, and silicates. The *The Pearson symbol* indicates the crystal symmetry and the number of atoms in the conventional unit cell. For example, rock salt NaCl structure has a face-centered (F) cubic (c) structure with 8 atoms in the cubic (nonprimitive!) unit cell, so it is designated $cF8$. The letters m, o, t, h, c are used in Pearson symbols for monoclinic, orthorhombic, tetragonal, hexagonal, trigonal, and cubic Bravais lattice types, respectively. Pearson symbols do not necessarily specify a unique structure: diamond, NaCl, and zincblende $cF8$ structures differ by symbols $A, B1$, and $B3$ (numbers in symbols $B1$ and $B3$ were assigned in roughly the historical order of the study of crystal lattices). The *prototype index* is an index of the various crystal structures by prototype compound (diamond, rock salt, zincblende structures). Some compounds can be associated with more than one prototype: ZnS compound can be found in zincblende and wurtzite structure. Finally, the *space group index* of a structure can be used. Space groups are listed in the order they appear in the International Tables [19]. As space groups refer to one of seven syngonies, the structures are ordered as triclinic (space groups 1 and 2), monoclinic (3–15), orthorhombic (16–74), tetragonal (75–142), trigonal (143–167), hexagonal (168–194), and cubic (195–230). For example, cubic structures correspond to the three Pearson symbols cPn, cFn , and cIn . In the next subsections, we give short descriptions of 15 types of crystal structures. We use space-group and prototype indices in subsection titles. In the corresponding tables, we give for each structure all the mentioned indices. These tables show that the same compound can be found in different structures (C —diamond, graphite; ZnS—sphalerite, wurtzite; CaTiO_3 —cubic perovskite, distorted (orthorhombic) perovskite; TiO_2 —rutile, anatase). Different structures can have the same Bravais lattice (diamond, NaCl, fluorite, sphalerite) or even the same space group (rock salt NaCl—fluorite CaF_2). For any structure type, we give the prototype, space group (number and international symbol), number of formula units in the primitive and conventional unit cells, the occupation of Wyckoff positions by atoms, and the equivalent Wyckoff-site description. This possibility of different equivalent descriptions of the crystal-structure types has to be taken into account when the symmetry of electron and phonon states in crystals is analyzed. Furthermore, when preparing the input data for modern computer codes (see Appendix C), one usually takes crystal-structure data from the database or original papers. These data often contain information about the structure in the form accepted in ICSD (Inorganic Crystal Structure Database); see site [20].

As an example, we take the data for rutile structure given in this database (in brackets some clarifications are given).

COL ICSD Collection Code 82656

DATE Recorded June 26, 1998; updated Nov 30, 1999

NAME Titanium dioxide

MINERAL Rutile—synthetic at 1,573 K

REFERENCE Journal of Solid State Chemistry 127 (1996) 240–247

CELL (lattice parameters for simple tetragonal lattice, unit cell volume, and number of formula units in conventional cell): $a = 4.594(0)$ $b = 4.594(0)$ $c = 2.959(0)$ $\alpha = 90.0$ $\beta = 90.0$ $\gamma = 90.0$ $V = 62.4$ $Z = 2$
 SGR (space group) $P 4_2/m n m$ (136)—tetragonal
 CLAS (point-symmetry group F of crystal) $4/m m m$ (Hermann–Mauguin)— D_{4h} (Schoenflies)
 PRS (Pearson symbol) tP6
 PARM (Wyckoff positions occupied by atoms and their parameters)

Atom	No	OxStat	Wyck	— — — X — — —	— — — Y — — —	— — — Z — — —
Ti	1	4.000	$2a$	0.	0.	0.
O	1	−2.000	$4f$	0.3047(2)	0.3047(2)	0.

As $Z = 2$ (two formula units in primitive unit cell, the conventional unit cell coincides with the primitive one as the Bravais lattice is simple tetragonal), one needs 2 sets of coordinates for Ti atom ($2a$) and four sets for O atom ($4f$). As is seen for each Wyckoff position occupied by an atom, there are given coordinates of only one representative. The others can be found on the site [16] for space group 136:

$$2a : (0, 0, 0) \left(\frac{1}{2}, \frac{1}{2}, \frac{1}{2} \right); 4f : (x, x, 0)(-x, -x, 0) \left(-x + \frac{1}{2}, x + \frac{1}{2}, \frac{1}{2} \right) \left(x + \frac{1}{2}, -x + \frac{1}{2}, \frac{1}{2} \right)$$

In this case, $x = 0.3047$ as follows from the structure data. To the best of our knowledge, only computer code CRYSTAL [21] allows one to include the space-group information in input data so that any occupied Wyckoff position can be presented by one representative. In the other computer codes, the coordinates of all atoms in the PUC are introduced, and the point symmetry of the structure is found by the code itself and used in calculations. From this example, it is seen that the necessary information for structures requires the use not only of the database but also IT.

Obviously, atoms of different chemical elements are always nonequivalent in a crystal, *that is*, cannot be connected by operations of symmetry. But atoms of one chemical element in a crystal cannot to be connected by operations of symmetry. These atoms are not equivalent in a crystal structure even when they occupy the same Wyckoff position with different free parameters (examples of such structures can be found in the next sections).

In the next sections, we briefly discuss the 15 crystal structures ordered by space-group index. There are included structures with both symmorphic and nonsymmorphic space groups, the structures with the same Bravais lattice and crystal class but different space groups, and structures described by only lattice parameters or by the lattice parameters and free parameters of the Wyckoff positions occupied by atoms.

A nonmathematical introduction to the key elements of the crystal-structure description can be found in the recently published book by Tilley [22]. As well as covering the basics, this book contains an introduction to areas of crystallography,

Table 2.5 Cubic structures^a

Prototype	Pearsons symbol	Strukturbericht designation	Space group	Wyckoff positions	Equivalent description
Diamond (C)	cF8	A4	Fd3m(227)	C(8a)	C(8b)
Rock salt (NaCl)	cF8	B1	$Fm\bar{3}m$ (225)	Na(4a) Cl(4b)	Na(4b) Cl(4a)
Fluorite (CaF ₂)	cF12	C1	$Fm\bar{3}m$ (225)	Ca(4a) F(8c)	Ca(4b) F(8c)
Zincblende (ZnS)	cF8	B3	F43m(216)	Zn(4a) S(4c)	Zn(4b) S(4d)
Cesium Chloride (CsCl)	cP2	B2	$Pm\bar{3}m$ (221)	Cs(1a) Cl(1b)	Cs(1b) Cl(1a)
Perovskite (cubic) (CaTiO ₃)	cP5	E21	$Pm\bar{3}m$ (221)	Ca(1a) Ti(1b) O(3c)	Ti(1a) Ca(1b) O(3d)

^a Equivalent sets of Wyckoff positions for space groups [16].

216 (abcd)(e)(fg)(h)(i)

221 (ab)(cd)(ef)(g)(h)(ij)(kl)(m)(n)

225 (ab)(c)(d)(e)(f)(g)(hi)(j)(k)(l)

227 (ab)(cd)(e)(f)(g)(h)(i)

such as modulated structures, quasicrystals, and protein crystallography, which are the subject of important and active research.

2.3.2 Cubic Structures: Diamond, Rock Salt, Fluorite, Zincblende, Cesium Chloride, and Cubic Perovskite

In Table 2.5, we give general information about all the cubic structures under consideration: prototype name, Pearson and Strukturbericht designations, space group and Wyckoff positions occupations, and possible equivalent description of the structure. All these structures contain one formula unit in the primitive unit cell ($Z = 1$). For the structures cF with a face-centered cubic lattice, the number of atoms is given for the cubic unit cell consisting of four primitive unit cells (this is traditional for crystal-structure databases). In computer calculations, only the atoms inside the primitive unit cell have to be included: two atoms for diamond, rock salt, zincblende, and cesium chloride structures and three and five atoms for fluorite and cubic perovskite structures, respectively.

Diamond structure (Fig. 2.5) is described by nonsymmorphic space group N227 with the face-centered cubic lattice: the macroscopic cubic symmetry of this crystal appears as the direct product of the first carbon atom site symmetry group T_d and

Fig. 2.5 Diamond structure

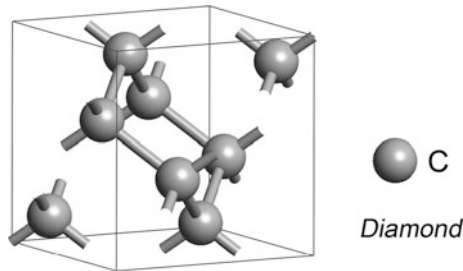
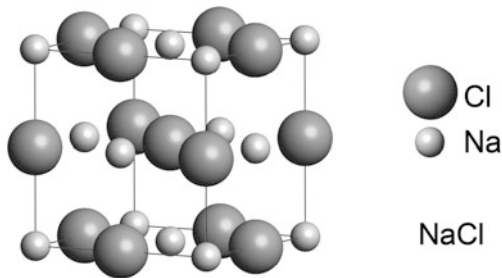


Fig. 2.6 NaCl structure



inversion I at the center of C–C bond moving the first carbon to the equivalent second carbon atom in the primitive unit cell.

The coordinates of the carbon atoms can be given in fractions of primitive lattice vectors (these vectors are nonorthogonal for a face-centered cubic lattice) or in Cartesian coordinates. The primitive vectors themselves are usually given in Cartesian coordinates that for cubic lattices are directed along the translation vectors of the conventional (cubic) unit cell (see Fig. 2.2). To describe the diamond structure, it is enough to give the numerical value of one parameter—the length of the cubic unit-cell translation vector (cubic lattice parameter a). One can find (<http://cst-www.nrl.navy.mil/lattice/>) the following numerical data for diamond structure (for an experimental value of 3.57 Å of the lattice parameter) in the form

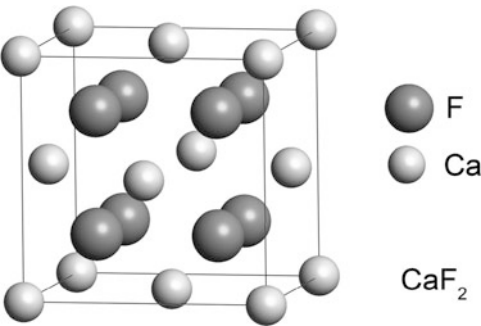
Primitive vectors $\mathbf{a}_1 = (0.000, 1.785, 1.785)$ $\mathbf{a}_2 = (1.785, 0.000, 1.785)$ $\mathbf{a}_3 = (1.785, 1.785, 0.000)$ Volume = 11.37482325

Atom	Lattice coordinates			Cartesian coordinates		
C	0.12500	0.12500	0.12500	0.44625	0.44625	0.44625
C	−0.12500	−0.12500	−0.12500	−0.44625	−0.44625	−0.44625

These numerical data correspond to the origin choice 2 for the space group N227 in [19] and the diamond structure description C(8a) with the shifted origin.

Rock salt NaCl structure (see Fig. 2.6) has the symmetry of symmorphic space group N225 and is typical of alkali halide crystals (Li, Na, K fluorides, chlorides, and bromides) and some oxides (MgO, CaO, SrO).

Fig. 2.7 Fluorite structure



The structure is defined also by only the face-centered cubic lattice parameter a (for NaCl crystal the experimental value of $a = 5.63 \text{ \AA}$):

Primitive vectors
 $\mathbf{a}_1 = (0.000, 2.815, 2.815)$
 $\mathbf{a}_2 = (2.815, 0.000, 2.815)$
 $\mathbf{a}_3 = (2.815, 2.815, 0.000)$
Volume = 44.61338675

Atom	Lattice coordinates			Cartesian coordinates		
Na	0.000	0.000	0.000	0.000	0.000	0.000
Cl	0.500	0.500	0.500	2.815	2.815	2.815

This description Na(4a)Cl(4b) is equivalent to the description in which the coordinates of atoms are interchanged.

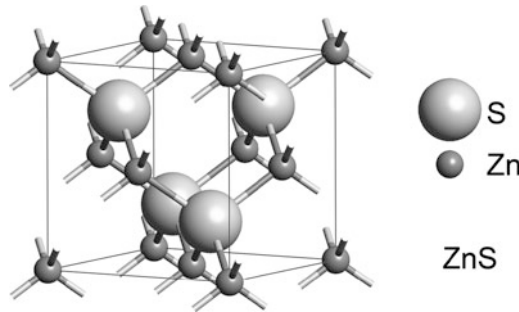
The same space group N225 is the symmetry group of the *fluorite* CaF₂ structure (Fig. 2.7).

Some compounds with this structure are the following: CO₂, CdF₂, CeO₂, SrCl₂, SrF₂, TiO₂, ZrO₂. For the experimental lattice parameter $a = 5.46295 \text{ \AA}$ the structure data are the following (Ca(4a)F(8c)):

Primitive vectors
 $\mathbf{a}_1 = (0.000000, 2.731475, 2.731475)$
 $\mathbf{a}_2 = (2.731475, 0.000000, 2.731475)$
 $\mathbf{a}_3 = (2.731475, 2.731475, 0.000000)$
Volume = 40.75882781

Atom	Lattice coordinates			Cartesian coordinates		
Ca	0.0000000	0.0000000	0.0000000	0.0000000	0.0000000	0.0000000
F	0.2500000	0.2500000	0.2500000	1.3657375	1.3657375	1.3657375
F	0.7500000	0.7500000	0.7500000	4.0972125	4.0972125	4.0972125

Fig. 2.8 Zincblende structure



The Ca atom in the fluorite structure can be placed also in Wyckoff position b (0.5,0.5,0.5). The same space group describes the symmetry of crystals (Li_2O , Na_2O) with so-called antifluorite structure: two cations occupy the Wyckoff position c and oxygen—the Wyckoff position a. The symmorphic space group N225 is given in [19] for one origin choice (in Wyckoff position a with the site symmetry group O_h).

The point symmetry of the *zincblende* ZnS (Fig. 2.8) structure is tetrahedral, but the lattice is cubic face-centered.

This structure can be obtained from the diamond structure by exchanging two carbon atoms with Zn and S atoms, so that the operation of interchange of two atoms in the primitive unit cell disappears. The zincblende structure is known for different compounds (AgI, AlAs, AlP, AlSb, BAs, BN, BP, BeS, BeSe, BeTe, CdS, CuBr, CuCl, CuF, CuI, GaAs, GaP, GaSb, HgS, HgSe, HgTe, INAs, InP, MnS, MnSe, SiC, ZnSe, ZnTe). For $a = 5.4093 \text{ \AA}$, the ZnS structure data are the following:

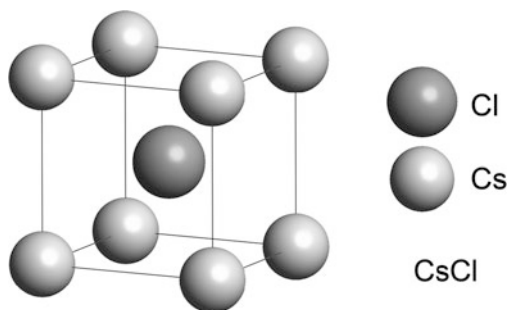
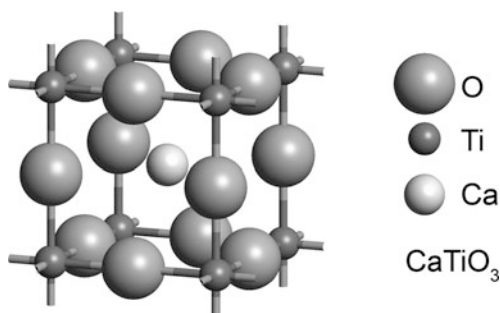
Primitive vectors
 $\mathbf{a}_1 = (0.00000, 2.70465, 2.70465)$
 $\mathbf{a}_2 = (2.70465, 0.00000, 2.70465)$
 $\mathbf{a}_3 = (2.70465, 2.70465, 0.00000)$
Volume = 39.56974149

Atom	Lattice coordinates			Cartesian coordinates		
Zn	0.000000	0.000000	0.000000	0.000000	0.000000	0.000000
S	0.250000	0.250000	0.250000	1.352325	1.352325	1.352325

For an equivalent description of the structure, the Zn and S atoms can be interchanged.

For the next two structures, the Bravais lattice is simple cubic.

Cesium chloride CsCl structure (Fig. 2.9) has the symmetry of symmorphic space group N221 and two equivalent descriptions Cs(1a)Cl(1b) and Cs(1b)Cl(1a). This structure was found for crystals CsBr, CsI, RbCl, AlCo, AgZn, BeCu, MgCe, RuAl, and SrTiI.

Fig. 2.9 CsCl structure**Fig. 2.10** Perovskite structure

For a simple cubic lattice parameter $a = 4.11 \text{ \AA}$ the CsCl crystal data are the following:

Primitive vectors

$$\mathbf{a}_1 = (4.11, 0.00, 0.00)$$

$$\mathbf{a}_2 = (0.00, 4.11, 0.00)$$

$$\mathbf{a}_3 = (0.00, 0.00, 4.11)$$

$$\text{Volume} = 69.42653100$$

Atom	Lattice coordinates			Cartesian coordinates		
Cs	0.000	0.000	0.000	0.000	0.000	0.000
Cl	0.500	0.500	0.500	2.055	2.055	2.055

In the equivalent description of this structure, the Cs and Cl atoms can be interchanged.

The *cubic perovskite* CaTiO_3 structure (Fig. 2.10) is more complicated and found as the high-temperature modification of different crystals (SrTiO_3 , BaTiO_3 , PbTiO_3 , SrZrO_3 , PbZrO_3).

The structure is defined by one simple cubic lattice parameter, and for $a = 3.795 \text{ \AA}$ five atoms in the CaTiO_3 unit cell have the following coordinates:

Primitive vectors

$$\mathbf{a}_1 = (3.795, 0.000, 0.000)$$

$$\mathbf{a}_2 = (0.000, 3.795, 0.000)$$

$$\mathbf{a}_3 = (0.000, 0.000, 3.795)$$

$$\text{Volume} = 54.65568$$

Atom	Lattice coordinates			Cartesian coordinates		
Ca	0.0000	0.0000	0.0000	0.0000	0.0000	0.0000
Ti	0.5000	0.5000	0.5000	1.8975	1.8975	1.8975
O	0.5000	0.0000	0.0000	1.8975	0.0000	0.0000
O	0.0000	0.5000	0.0000	0.0000	1.8975	0.0000
O	0.0000	0.0000	0.5000	0.0000	0.0000	1.8975

In the cubic perovskite structure, the Ti–O distance is equal to one half of the translation vector length. In the equivalent structure description (when Ca and Ti atoms are interchanged), the three oxygen atom positions need to be taken as (0.5 0.5 0), (0.5,0,0.5), and (0,0.5,0.5).

The considered different cubic structures are defined by one numerical parameter—the cubic lattice constant. This is due to the fact that in these structures atoms occupy Wyckoff positions that have no free parameters. The definition of the more complicated structures requires the knowledge of both the lattice constants and the numerical values of the free parameters for the free-parameter-dependent Wyckoff positions occupied by atoms.

2.3.3 Tetragonal Structures: Rutile, Anatase, and La_2CuO_4

In Table 2.6, we give general information about three tetragonal structures: two modifications (rutile and anatase) of titanium dioxide TiO_2 and lanthanum cuprate La_2CuO_4 .

The rutile and anatase phases of titanium dioxide have been widely studied in recent years. The rutile form is used as a white pigment and opacifier; the anatase phase finds applications in photo catalysts and nanostructured solar cells. La_2CuO_4 has attracted considerable research efforts as it was found to become a high- T_c superconductor ($T_c = 35$ K) when properly doped with Sr or Ba atoms. Both TiO_2 modifications contain 6 atoms (two formula units) in the primitive cell.

The rutile structure (Fig. 2.11) belongs to the $P4_2/mnm$ nonsymmorphic space group.

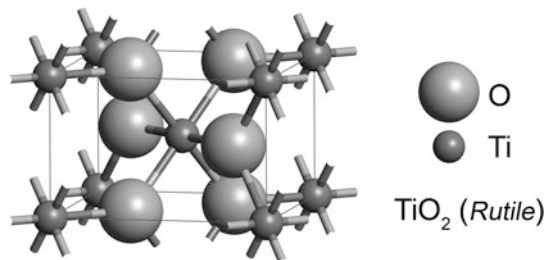
The unit cell of the primitive tetragonal lattice is defined by the lattice vectors $\mathbf{a}_1 = \mathbf{a}_2$ (in the xy -plane) and $\mathbf{c}$ (along z -axis). The rotations through a fourth-order axis are followed by the improper translations along the z -axis of one-half of the $\mathbf{c}$ -vector length to ensure transformation of any of the oxygen atoms to another one; see Table 2.4. As is seen from Table 2.6, two Ti atoms of the primitive cell occupy Wyckoff position a(000;1/2,1/2,1/2), and four oxygen atoms occupy Wyckoff position f with one free-parameter u : $(\pm(u, u, 0); \pm(u+1/2, 1/2-u, 1/2))$.

Table 2.6 Tetragonal structures^a

Prototype	Pearsons symbol	Strukturbericht designation	Space group	Wyckoff positions	Equivalent description
Rutile (TiO ₂)	tP6	C4	$P4_2/mnm(136)$	Ti(2a) O(4f)	Ti(2b) O(4g)
Anatase (TiO ₂)	tI12	C5	$I4_1/amd(141)$	Ti(2a) O(4e)	Ti(2b) O(4e)
Lanthanum cuprate (La ₂ CuO ₄)	tI14	–	$I4/mmm(139)$	La(2e) Cu(1a) O ₁ (2c) O ₂ (2e)	La(2e) Cu(1b) O ₁ (2c) O ₂ (2e)

^a Equivalent sets of Wyckoff positions for space groups [16].
136 (ab)(c)(d)(e)(fg)(h)(i)(j)(k)
141 (ab)(cd)(e)(f)(g)(h)(i)
139 (ab)(c)(d)(f)(e)(g)(h)(ij)(k)(l)(m)(n)(o)

Fig. 2.11 Rutile structure

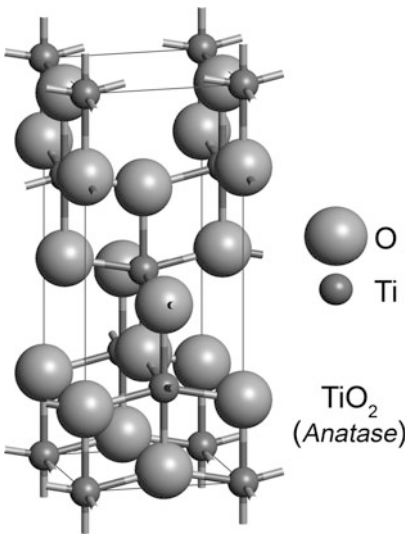


The Wyckoff positions coordinates are given in units of a , a , c . Thus, the rutile structure is defined by three parameters: a , c , and u . The following numerical data for rutile structure are given in <http://cst-www.nrl.navy.mil/lattice/>:

Primitive vectors
 $\mathbf{a}_1 = (4.59373, 0.00000, 0.00000)$
 $\mathbf{a}_2 = (0.00000, 4.59373, 0.00000)$
 $\mathbf{a}_3 = (0.00000, 0.00000, 2.95812)$
Volume = 62.42329930

Atom	Lattice coordinates			Cartesian coordinates		
Ti	0.0000	0.0000	0.0000	0.00000000	0.00000000	0.00000
Ti	0.5000	0.5000	0.5000	2.29686500	2.29686500	1.47906
O	0.3053	0.3053	0.0000	1.40246577	1.40246577	0.00000
O	−0.3053	−0.3053	0.0000	−1.40246577	−1.40246577	0.00000
O	0.8053	0.1947	0.5000	3.69933077	0.89439923	1.47906
O	0.1947	0.8053	0.5000	0.89439923	3.69933077	1.47906

Fig. 2.12 Anatase structure

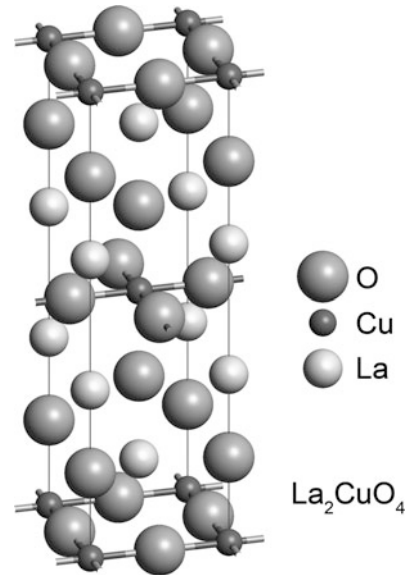


The *anatase* structure (Fig. 2.12) belongs to the $I4_1/amd$ nonsymmorphic space group.

The tetragonal unit cell of a body-centered tetragonal lattice is defined by the lattice vectors $\mathbf{a}_1 = \mathbf{a}_2$ (in the xy -plane) and $\mathbf{c}$ (along the z -axis) and contains two primitive unit cells (see Fig. 2.2). To describe the primitive unit cell the translation vectors $\mathbf{a}_1(a, 0, 0)$, $\mathbf{a}_2(0, a, 0)$, $\mathbf{a}_3(1/2a, 1/2a, 1/2c)$ are used. As is seen from Table 2.6, two Ti atoms of the primitive cell occupy Wyckoff position $2a(0, 0, 0; 0, 1/2, 1/4)$, and four oxygen atoms occupy Wyckoff position $4e(0, 0, u; 1/2, 0, -u + 1/2; 0, 1/2, u + 1/4; 1/2, 1/2, -u + 1/2)$. The anatase structure is defined by three parameters: a , c , and u . The numerical data for anatase structure, given in <http://cst-www.nrl.navy.mil/lattice/>, are the following:

Primitive vectors
 $\mathbf{a}_1 = (3.7850, 0.0000, 0.0000)$
 $\mathbf{a}_2 = (0.0000, 3.7850, 0.0000)$
 $\mathbf{a}_3 = (1.8925, 1.8925, 4.7570)$
Volume = 68.14985232

Atom	Lattice coordinates			Cartesian coordinates		
Ti	0.125	-0.125	-0.25	0.0000	-0.94625	-1.18925
Ti	0.125	0.125	0.25	0.0000	0.94625	1.18925
O	0.08159975	0.33159975	-0.16319950	0.0000	0.94625	-0.77634
O	-0.08159975	-0.33159975	0.16319950	0.0000	-0.94625	0.77634
O	0.33159975	0.08159975	0.33680050	1.8925	0.94625	1.602160
O	-0.33159975	-0.08159975	-0.33680050	-1.8925	-0.94625	-1.60216

Fig. 2.13 La_2CuO_4 structure

These data correspond to the coordinate system origin shifted by $(1/8, -1/8, -1/4)$ (in the units of primitive translations), in comparison with the origin choice made in [19].

The *lanthanum cuprate* structure (Fig. 2.13) belongs to the symmorphic space group $I4/mmm$ with the body-centered tetragonal lattice and contains seven atoms in the primitive unit cell.

The Cu atom occupies Wyckoff position $1a(000)$ and two La atoms and two oxygen atoms O_2 occupy Wyckoff position $2e \pm(0, 0, z)$ with different numerical values of the z parameter for La and oxygen atoms; the two remaining oxygen atoms occupy Wyckoff position $2c(0, 1/2, 0; 1/2, 0, 0)$. The structure is defined by two tetragonal lattice parameters (lengths of $\mathbf{a}_1 = \mathbf{a}_2$ primitive translations and $\mathbf{c}$ —translation vector of the tetragonal unit cell containing two primitive cells) and two z parameters defining the positions of the La and O_2 atoms. The numerical data for this structure are taken from <http://cst-www.nrl.navy.mil/lattice/>. The primitive translation vector $\mathbf{a}_3(1/2, 1/2, 1/2)$ is given in units of a, a, c .

Primitive vectors

$$\mathbf{a}_1 = (3.78730, 0.00000, 0.00000)$$

$$\mathbf{a}_2 = (0.00000, 3.78730, 0.00000)$$

$$\mathbf{a}_3 = (1.89365, 1.89365, 6.64415)$$

$$\text{Volume} = 95.30130$$

The La_2CuO_4 structure (see Fig. 2.13) consists of $\text{CuO}_2\text{--La--O--O--La}$ planes repeated along the z -axis (translation vector $\mathbf{c}$).

Atom	Cartesian coordinates			Free parameter z
Cu	0.00000000	0.00000000	0.00000000	0.3606
La	0.00000000	0.00000000	4.79176098	
La	0.00000000	0.00000000	8.49653902	
O ₁	1.89365000	0.00000000	0.00000000	0.1828
O ₁	0.00000000	1.89365000	0.00000000	
O ₂	0.00000000	0.00000000	2.42910124	
O ₂	0.00000000	0.00000000	10.85919876	

Table 2.7 Orthorhombic structures^a

Prototype	Space group	Wyckoff positions	Equivalent description
LaMnO ₃	Pnma(62)	La(4c)	La(4c)
		Mn(4a)	Mn(4b)
		O1(4c)	O1(4c)
		O2(8d)	O2(8d)
YBa ₂ Cu ₃ O ₇	Pmmm(47)	Y(1h)	Y(1a)
		Ba(2t)	Ba(2q)
		Cu ₁ (1a)	Cu ₁ (1h)
		Cu ₂ (2q)	Cu ₂ (2t)
		O ₁ (1e)	O ₁ (1d)
		O ₂ (2r)	O ₂ (2s)
		O ₃ (2s)	O ₃ (2r)
		O ₄ (2q)	O ₄ (2t)

^a Equivalent sets of Wyckoff positions for space groups [16].

62 Pnma (ab)(c)(d)

47 Pmmm (abcdefgh)(ijklmnopqrst)(uvwxyz)

The electronic structure calculations show (see Chap. 9): the highest occupied band states in the lanthanum cuprate are $O_1 - 2p_x, 2p_y$ states strongly mixed with $Cu - 3d_{x^2-y^2}$ states. This result agrees with the hypothesis that the high- T_c conductivity can be explained by CuO_2 -plane consideration as is done in most theoretical models.

2.3.4 Orthorhombic Structures: LaMnO₃ and YBa₂Cu₃O₇

In Table 2.7, we give the information about two orthorhombic structures: lanthanum manganite LaMnO₃ (Fig. 2.14) and yttrium cuprate YBa₂Cu₃O₇ (Fig. 2.15).

Among the manganese oxides, LaMnO₃ is important as it is the parent system in the family of manganites that show colossal magnetoresistance effects. In the low-temperature phase, this crystal belongs to the nonsymmorphic space group N62 with the simple orthorhombic lattice. There are four formula units (20 atoms) in the

Fig. 2.14 Orthorhombic LaMnO_3 structure

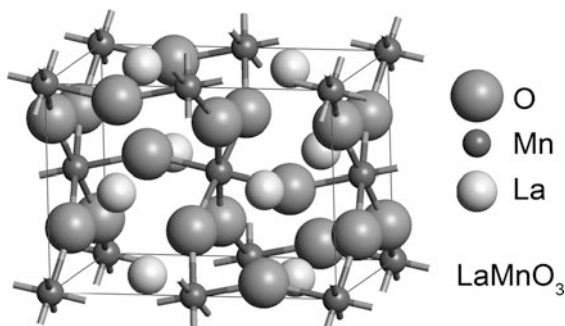
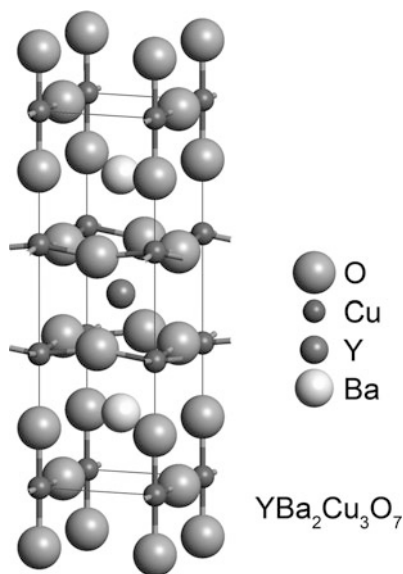


Fig. 2.15 $\text{YBa}_2\text{Cu}_3\text{O}_7$ structure



primitive unit cell. The structure parameters can be found in the literature in two different settings used for the nonsymmorphic space group $N62$ description. In the standard setting Pnma (accepted in [19]), the primitive orthorhombic lattice vectors $\mathbf{a}$, $\mathbf{b}$, $\mathbf{c}$ define the following Wyckoff positions occupied by atoms: La $4c(x, 1/4, z)$, Mn $4a(0,0,0; 1/2,0,1/2; 0,1/2,0; 1/2,1/2,1/2)$, O_1 $4c(x, 1/4, z; 1/2 - x, -1/4, 1/2 + z; -x, -1/4, -z; x + 1/2, 1/4, 1/2 - z)$, and O_2 $8d(x, y, z)$. The Pbnm setting means the cyclic transposition of basic translation vectors $\mathbf{a}$, $\mathbf{b}$, $\mathbf{c}$ to $\mathbf{c}$, $\mathbf{a}$, $\mathbf{b}$ and the corresponding changes in the Wyckoff positions coordinates: $c(z, x, 1/4)$ and $d(z, x, y)$. When using the structure data from the literature, one has to take into account the setting chosen. The structure is defined by three orthorhombic lattice parameters and 7 internal parameters: two parameters x , z for La and O_1 atoms and 3 parameters for O_2 atoms. The equivalent description of LMO structure given in

Table 2.7 for the fixed setting means in fact the change of the coordinate system origin—moving the Mn atom position from $a(000)$ to $b(001/2)$. The coordinates of c and d points has to be also changed to $(x, 1/4, z + 1/2)$, $d(x, y, z + 1/2)$. In this case, the structure parameters do not change.

Taken from <http://cst-www.nrl.navy.mil/lattice/>, the structure data are given in the Pnma setting.

Primitive vectors

$$\mathbf{a}_1 = (5.6991, 0.0000, 0.0000)$$

$$\mathbf{a}_2 = (0.0000, 7.7175, 0.0000)$$

$$\mathbf{a}_3 = (0.0000, 0.0000, 5.5392)$$

$$\text{Volume} = 243.62954930$$

Atom	Lattice coordinates			Cartesian coordinates		
Mn	0.00000000	0.00000000	0.00000000	0.00000000	0.00000000	0.00000000
Mn	0.50000000	0.00000000	0.50000000	2.84955000	0.00000000	2.76960000
Mn	0.00000000	0.50000000	0.00000000	0.00000000	3.85875000	0.00000000
Mn	0.50000000	0.50000000	0.50000000	2.84955000	3.85875000	2.76960000
La	0.54349985	0.25	0.00636915	3.09746000	1.92938000	0.03528000
La	−0.04349985	0.75	0.50636915	−0.24791000	5.78812000	2.80488000
La	−0.54349985	0.75	−0.00636915	−3.09746000	5.78812000	−0.03528000
La	1.04349985	0.25	0.49363085	5.94701000	1.92938000	2.73432000
O ₁	−0.01069994	0.25	−0.07329939	−0.06098000	1.92938000	−0.40602000
O ₁	0.51069994	0.75	0.42670061	2.91053000	5.78812000	2.36358000
O ₁	0.01069994	0.75	0.07329939	0.06098000	5.78812000	0.40602000
O ₁	0.48930006	0.25	0.57329939	2.78857000	1.92938000	3.17562000
O ₂	0.30140022	0.03849951	0.22570046	1.71771000	0.29712000	1.25020000
O ₂	0.19859978	−0.03849951	0.72570046	1.13184000	−0.29712000	4.01980000
O ₂	−0.30140022	0.53849951	−0.22570046	−1.71771000	4.15587000	−1.25020000
O ₂	0.80140022	0.46150049	0.27429954	4.56726000	3.56163000	1.51940000
O ₂	−0.30140022	−0.03849951	−0.22570046	−1.71771000	−0.29712000	−1.25020000
O ₂	0.80140022	0.03849951	0.27429954	4.56726000	0.29712000	1.51940000
O ₂	0.30140022	0.46150049	0.22570046	1.71771000	3.56163000	1.25020000
O ₂	0.19859978	0.53849951	0.72570046	1.13184000	4.15587000	4.01980000

The Y–Ba–Cu–O systems are known as high- T_c superconductors ($T_c = 93$ K) when oxygen atoms in the $\text{YBa}_2\text{Cu}_3\text{O}_7$ system are partly replaced by vacancies or fluorine atoms to synthesize ceramic oxides $\text{YBa}_2\text{Cu}_3\text{O}_{7-x}$. The atomic structure of this compound is described by symmorphic space group Pmmm, the primitive unit cell of the orthorhombic lattice consists of one formula unit with the atoms distributed over several planes (see Fig. 2.15). The three copper atoms form two nonequivalent groups: Cu₁ atom occupies Wyckoff position 1a(0,0,0), forming Cu–O chains and two Cu₂ atoms—Wyckoff position 2q(0,0,±z) (see Table 2.7), forming CuO₂ planes. Two Ba atoms occupy 2t(1/2,1/2,±z) position. The seven

oxygens form four nonequivalent atomic systems: $O_1—1e(0,1/2,0)$, $O_2—2r(0,1/2,\pm z)$, $O_3—2s(1/2,0,\pm z)$, and $O_4—2q(0,0,\pm z)$. The structure requires eight parameters for its definition: three orthorhombic lattice parameters and five internal parameters of Ba, Cu₂, and O₂, O₃, and O₄ atomic positions. All the structural data from <http://cst-www.nrl.navy.mil/lattice/> are the following:

Primitive vectors

$$\mathbf{a}_1 = (3.8227, 0.0000, 0.0000)$$

$$\mathbf{a}_2 = (0.0000, 3.8872, 0.0000)$$

$$\mathbf{a}_3 = (0.0000, 0.0000, 11.6802)$$

$$\text{Volume} = 173.56308$$

Atom	Cartesian coordinates			Free parameter z (in $ \mathbf{a}_3 $ units)
Cu ₁	0.00000000	0.00000000	0.00000000	0.3556
Cu ₂	0.00000000	0.00000000	4.15347912	
Cu ₂	0.00000000	0.00000000	7.52672088	
O ₁	0.00000000	1.94360000	0.00000000	0.3790
O ₂	0.00000000	1.94360000	4.42679580	
O ₂	0.00000000	1.94360000	7.25340420	
O ₃	1.91135000	0.00000000	4.41394758	0.3779
O ₃	1.91135000	0.00000000	7.26625242	
O ₄	0.00000000	0.00000000	1.85715180	0.1590
O ₄	0.00000000	0.00000000	9.82304820	
Ba	1.91135000	1.94360000	2.15266086	0.1843
Ba	1.91135000	1.94360000	9.52753914	

2.3.5 Hexagonal and Trigonal Structures: Graphite, Wurtzite, Corundum, and ScMnO₃

In this section we consider three hexagonal (graphite, wurtzite, and ScMnO₃, see Figs. 2.16–2.18, respectively) and one trigonal (corundum) structure; see Fig. 2.19.

The latter structure can also be described in hexagonal axes (Table 2.8).

The graphite structure belongs to the nonsymmorphic space group P6₃/mmc, the primitive unit cell of the hexagonal lattice contains 4 carbon atoms occupying two nonequivalent Wyckoff positions: 2a (0,0,0;0,0,1/2) and 2b(0,0,1/4;0,0,–1/4). The structure is described by two hexagonal lattice parameters a and c . The graphite structure consists of atomic layers separated by a distance larger than the interatomic distance in one layer. Therefore, the one-layer approximation is in some cases used for graphite: only two carbon atoms in the primitive cell of the plane hexagonal lattice are included in the structure.

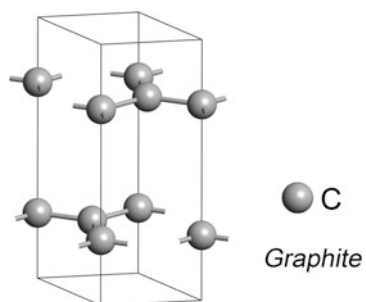
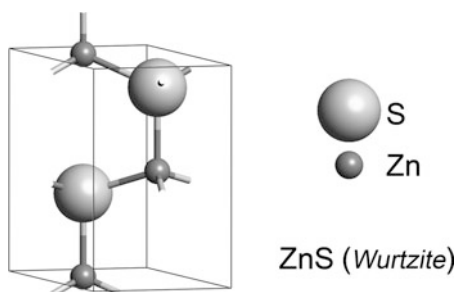
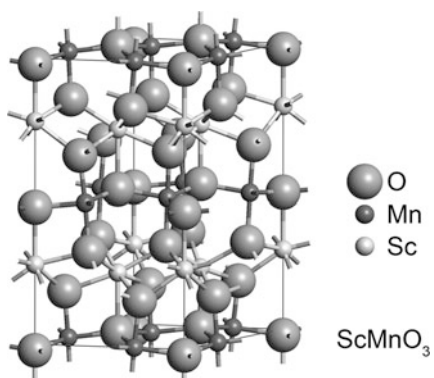
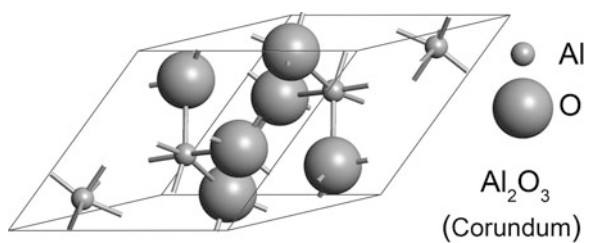
Fig. 2.16 Graphite structure**Fig. 2.17** Wurtzite structure**Fig. 2.18** ScMnO_3 structure**Fig. 2.19** Corundum structure

Table 2.8 Hexagonal structures^a

Prototype	Pearsons symbol	Strukturbericht designation	Space group	Wyckoff positions	Equivalent description
Graphite C	hP4	A9	$P6_3/mmc$ (194)	C(2a) C(2b)	–
Wurtzite (ZnS)	hP4	B4	$P6_3mc$ (186)	Zn(2b) S(2b)	–
ScMnO ₃	hP30	–	$P6_3cm$ (185)	Sc ₁ (2a) Sc ₂ (4b) Mn(6c) O ₁ , O ₂ (6c) O ₃ (2a) O ₄ (4b)	–
Corundum (Al ₂ O ₃)	hR10	D5 ₁	$R\bar{3}c$ (167)	Al(4c) O(6e)	–

^a Equivalent sets of Wyckoff positions for space groups [16].

194 (a)(b)(cd)(e)(f)(g)(h)(i)(j)(k)(l)

186 (a)(b)(c)(d)

185 (a)(b)(c)(d)

167 (a)(b)(c)(d)(e)(f)

The numerical values of the graphite structure data from <http://cst-www.nrl.navy.mil/lattice/> are the following:

Primitive vectors

$$\mathbf{a}_1 = (1.22800000, -2.12695839, 0.00000000)$$

$$\mathbf{a}_2 = (1.22800000, 2.12695839, 0.00000000)$$

$$\mathbf{a}_3 = (0.00000000, 0.00000000, 6.69600000)$$

$$\text{Volume} = 34.97863049$$

Atom	Lattice coordinates			Cartesian coordinates		
C	0.00000000	0.00000000	0.25000000	0.00000000	0.00000000	1.67400000
C	0.00000000	0.00000000	0.75000000	0.00000000	0.00000000	5.02200000
C	0.33333333	0.66666667	0.25000000	1.22800000	0.70898613	1.67400000
C	0.66666667	0.33333333	0.75000000	1.22800000	-0.70898613	5.02200000

The wurtzite structure of ZnS is the hexagonal analog of the zincblende structure of ZnS (see Sect. 3.2.2) and belongs to the nonsymmorphic space group $P6_3mc$ with a hexagonal lattice. The primitive unit cell contains two formula units; both Zn and S atoms occupy the same Wyckoff position $2b(1/3, 2/3, z; 2/3, 1/3, z + 1/2)$ with the different values of internal parameter z . Thus, the wurtzite structure is defined by 4 parameters—two lattice and two internal ones. The numerical values of the structure data from <http://cst-www.nrl.navy.mil/lattice/> are the following:

Primitive vectors

$$\mathbf{a}_1 = (1.91135000, -3.31055531, 0.00000000)$$

$$\mathbf{a}_2 = (1.91135000, 3.31055531, 0.00000000)$$

$$\mathbf{a}_3 = (0.00000000, 0.00000000, 6.26070000)$$

$$\text{Volume} = 79.23078495$$

Atom	Lattice coordinates			Cartesian coordinates		
Zn	0.33333333	0.66666667	0.00000000	1.91135000	1.10351844	0.00000000
Zn	0.66666667	0.33333333	0.50000000	1.91135000	-1.10351844	3.13035000
S	0.33333333	0.66666667	0.37480000	1.91135000	1.10351844	2.34651036
S	0.66666667	0.33333333	-0.12520000	1.91135000	-1.10351844	-0.78383964

RMnO_3 rare-earth *manganites* show a wide variety of physical properties. For R^{3+} cations with large ionic size, RMnO_3 oxides crystallize in a perovskite-type structure, with orthorhombic symmetry, as was illustrated in Sect. 2.3.4 by the example of LaMnO_3 manganite. For $\text{R} = \text{Y}, \text{Sc}, \text{Ho-Lu}$, the perovskite structure becomes metastable and a new hexagonal polytype stabilizes. The hexagonal manganites are an interesting group of compounds because of their unusual combination of electrical and magnetic properties: at low temperatures they show coexistence of ferroelectric and magnetic orderings. ScMnO_3 plays a prominent role in this series. It has the highest Neel temperature and the smallest distance between magnetic ions Mn^{3+} along the hexagonal axis direction. At temperatures below 1,200 K, ScMnO_3 structure belongs to space group $\text{P6}_3\text{cm}$ with hexagonal lattice and six formula units (30 atoms) per cell. The six Mn atoms occupy Wyckoff position $6c(x, 0, z; 0, x, z; -x, -x, z; -x, 0, z + 1/2; 0, -x, z + 1/2; x, x, z + 1/2)$. The six Mn atoms are distributed in the $z = 0$ and $z = 1/2$ planes. Each Mn atom occupies the center of a triangular bipyramid whose vertices are oxygen atoms (see Fig. 2.18). As a result, each Mn atom is coordinated by five oxygen atoms in a bipyramidal configuration. The same Wyckoff position $6c$ is occupied by nonequivalent (with the different internal parameters x, z) oxygens O_1, O_2 . Sc_1 , and O_3 atoms occupy Wyckoff position $2a(0, 0, z; 0, 0, z + 1/2)$, Sc_2 , and O_4 atoms—Wyckoff position $4b(1/3, 2/3, z; 2/3, 1/3, z + 1/2; 1/3, 2/3, z + 1/2; 2/3, 1/3, z)$. One O_3 atom and two O_4 atoms are in the equatorial plane of the bipyramid, whereas the O_1 and O_2 atoms are at the apices. Sc atoms occupy two crystallographic positions Sc_1 and Sc_2 , both of them bonded to seven oxygen atoms. Both RO_7 polyhedra can be described as monocapped octahedra. The capping oxygens are O_3 for Sc_1 and O_4 for Sc_2 . Along the axis z , the structure consists of layers of corner-sharing MnO_5 bipyramids separated by layers of edge-sharing RO_7 polyhedra. The structure is defined by two hexagonal lattice parameters and 10 internal parameters—two for each type of atoms Mn, O_1 , and O_2 and one for each type of atoms $\text{Sc}_1, \text{Sc}_2, \text{O}_3$, and O_4 . The numerical values of all the structure parameters can be found, for example, in [23]. The description of the ScMnO_3 shows it as a very complicated one with many atoms in the primitive cell. Nevertheless, the first-principles LCAO calculations of ScMnO_3 were recently made (see Chap. 9). *Aluminum oxide* ($\alpha\text{-Al}_2\text{O}_3$, *corundum*) has a large number of technological applications. Due to its hardness, its chemical and mechanical stability at high temperatures, and its electronic properties as

a widegap insulator, it is used for the fabrication of abrasives, as a carrier for thin metal films in heterogeneous catalysis and in optical and electronic devices. $\alpha - \text{Al}_2\text{O}_3$ crystallizes in a rhombohedral structure with the space group $R\bar{3}c$. The primitive rhombohedral unit cell consists of two Al_2O_3 units with experimental lattice parameters $a = 5.128 \text{ \AA}$ and $\alpha = 55.333^\circ$. Four Al atoms occupy Wyckoff position 4c: $\pm(x, x, x; -x + 1/2, -x + 1/2, -x + 1/2)$. Six oxygen atoms occupy Wyckoff position 6e: $\pm(x, -x + 1/2, 1/4; 1/4, x, -x + 1/2; -x + 1/2, 1/4, x)$. Using the transformation of the rhombohedral lattice vectors with the matrix (2.10), one obtains the hexagonal setting of the $\alpha - \text{Al}_2\text{O}_3$ structure. Its unit cell consists of three primitive unit cells (the determinant of the transformation matrix equals 3). The lattice parameters in this hexagonal setting are $a = 4.763 \text{ \AA}$, $c = 13.003 \text{ \AA}$. In hexagonal axes, the positions occupied by atoms are written in the form 4c $\pm(0, 0, z; 0, 0, -z + 1/2)$ and 6e $\pm(x, 0, 1/4; 0, x, 1/4; -x, -x, 1/4)$. The two internal parameters of the corundum structure define the Al and O atoms positions; in terms of the hexagonal lattice, $x_{\text{Al}}(\text{hex}) = 0.35228$, and $x_{\text{O}}(\text{hex}) = 0.306$. On the rhombohedral lattice, this translates to $z_1 = x_{\text{Al}}(\text{hex}) = 0.35228$ and $x_1 = 1/4 - x_{\text{O}}(\text{hex}) = -0.0564$. In rhombohedral axes, the numerical data for corundum structure are given, for example, in <http://cst-www.nrl.navy.mil/lattice/>:

Primitive rhombohedral vectors

$$\mathbf{a}_1 = (0.256984, 3.621398, 3.621398)$$

$$\mathbf{a}_2 = (3.621398, 0.256984, 3.621398)$$

$$\mathbf{a}_3 = (3.621398, 3.621398, .256984)$$

$$\text{Volume} = 84.89212148$$

Atom	Lattice coordinates			Cartesian coordinates		
Al	0.35228000	0.35228000	0.35228000	2.64202250	2.64202250	2.64202250
Al	-0.35228000	-0.35228000	-0.35228000	-2.64202250	-2.64202250	-2.64202250
Al	0.14772000	0.14772000	0.14772000	1.10786750	1.10786750	1.10786750
Al	-0.14772000	-0.14772000	-0.14772000	-1.10786750	-1.10786750	-1.10786750
O	-0.05640000	0.55640000	0.25000000	2.90580145	0.84408855	1.87494500
O	0.05640000	-0.55640000	-0.25000000	-2.90580145	-0.84408855	-1.87494500
O	0.55640000	0.25000000	-0.05640000	0.84408855	1.87494500	2.90580145
O	-0.55640000	-0.25000000	0.05640000	-0.84408855	-1.87494500	-2.90580145
O	0.25000000	-0.05640000	0.55640000	1.87494500	2.90580145	0.84408855
O	-0.25000000	0.05640000	-0.55640000	-1.87494500	-2.90580145	-0.84408855

By consideration of the hexagonal and trigonal structures, we conclude the discussion of the structure definitions by space groups and Wyckoff positions. In the next chapter, we consider the symmetry of crystalline orbitals, both canonical and localized.

Chapter 3

Symmetry and Localization of Crystalline Orbitals

The quantum chemistry of solids mainly deals with those physical and chemical properties of solids that depend on the electronic structure. The approximate many-electron function is introduced in such a way that electron subsystem calculations are made for one-electron Bloch wavefunctions (crystalline orbitals), numbered by the wavevector $\mathbf{k}$. The dimension of a space-group full representation (degeneracy of energy levels in a crystal) for a given $\mathbf{k}$ is equal to the product of the number of rays in the star $\mathbf{k}^*$ and the dimension of the point-group $F_{\mathbf{k}}$ irreducible representation (ordinary or projective). The information about the symmetry connection between the atomic and crystalline states is widely used in the quantum chemistry of solids as it allows the crystalline properties to be explained from the knowledge of the chemical nature of the constituent atoms and their interactions. The symmetry connection of the localized atomic functions and delocalized Bloch functions is defined from the tables of the irreducible representations of space groups induced by the irreducible representations of point groups for Wyckoff positions occupied by the atoms in the crystalline structure. This site-symmetry approach is useful in orthonormalized localized crystalline orbital (Wannier functions) generation from canonical delocalized Bloch functions. The variational method is discussed, which assures the best localization of the generated Wannier functions.

3.1 Translation and Space Symmetry of Crystalline Orbitals: Bloch Functions

3.1.1 Symmetry of Molecular and Crystalline Orbitals

In a previous chapter we considered the symmetry of a crystalline structure for fixed nuclei positions. The aim of the first-principles approaches in quantum chemistry is to calculate the properties of molecules and crystals without the use of empirical

parameters. In principle, all the particles—electrons and nuclei—should be involved in such calculations. In fact, the solution of this complicated task is simplified in the Born–Oppenheimer approximation (also called the adiabatic approximation). In the first stage the electronic subsystem is studied for different nuclear configurations to calculate the potential-energy surface and to find the optimized atomic positions corresponding to the minimal total energy per primitive cell. The nuclear motion can be studied *a posteriori* by considering the electronic energy surface as an external potential. Quantum chemistry of solids concerns mainly those physical and chemical properties of solids that depend on the electronic structure. The problem of nuclear motion is solved in approaches using molecular-dynamics methods [24]. These approaches (not considered in this book) allow the study of thermodynamic and transport properties of solids and deserve a separate monograph. The calculations of the electronic subsystem in the adiabatic approximation are always connected with the choice of the electronic Hamiltonian. Formally, the symmetry of the electronic Hamiltonian may differ from the symmetry of the nuclear configuration. However, in the case of crystalline solids, the approximate electronic Hamiltonians are usually chosen in such a way that the translational and point symmetry of a crystal is maintained. In Chaps. 4–6 we consider in more detail two of the mostly popular approximate methods of many-electron systems description—Hartree–Fock method and the density-functional theory. In both approaches the approximate many-electron function is introduced in such a way that the electron subsystem calculations are made for one-electron wavefunctions. The latter are known as molecular orbitals in molecules and crystalline orbitals in crystals. The symmetry of the electronic Hamiltonian ensures that orbitals (one-electron functions for many-electron systems) transform according to the irreducible representations of point groups for molecules and space groups for crystals. Let the wavefunction $\varphi(\mathbf{r})$ depend on the coordinates of only one electron; $\hat{H}$ is a Hamiltonian operator and E the energy of the eigenstate $\varphi(\mathbf{r})$. The function $\varphi(\mathbf{r})$ satisfies the time-independent equation

$$\hat{H}(\mathbf{r})\varphi(\mathbf{r}) = E\varphi(\mathbf{r}) \quad (3.1)$$

The transformation g is said to be a symmetry operation of the Hamiltonian $\hat{H}$ if $\hat{H}(g^{-1}\mathbf{r}) = \hat{H}(g\mathbf{r})$, *that is*, if $\hat{H}$ is invariant under g . Symmetry operations g that leave $\hat{H}$ invariant form a group. This group is called the symmetry group of the Hamiltonian or of the Schrodinger equation (3.1).

We introduce in the linear vector space L of functions $\varphi(\mathbf{r})$ the operators $\hat{g} = \hat{D}(g)$ as

$$\hat{D}(g)\varphi(\mathbf{r}) = \hat{g}\varphi(\mathbf{r}) = \varphi(g^{-1}\mathbf{r}) \quad (3.2)$$

The operators $\hat{g}$ are linear, and the correspondence $g \rightarrow \hat{g}$ is preserved in the composition law:

$$\hat{g}_2\hat{g}_1\varphi(\mathbf{r}) = \hat{g}_2\varphi(g_1^{-1}\mathbf{r}) = \varphi(g_1^{-1}g_2^{-1}\mathbf{r}) = \varphi((g_2g_1)^{-1}\mathbf{r}) \quad (3.3)$$

Hence, the set of operators $\hat{D}(g) = \hat{g}(g \in G)$ is a rep of G , and L is the space of this rep. If $g \in G$ is a symmetry operation of the Hamiltonian operator $\hat{H}$, then

$$\hat{H}(\mathbf{r})\hat{g}\varphi(\mathbf{r}) = \hat{H}(\mathbf{r})\varphi(g^{-1}\mathbf{r}) = E\varphi(g^{-1}\mathbf{r}) = \hat{g}E\varphi(\mathbf{r}) = \hat{g}\hat{H}\varphi(\mathbf{r}) \quad (3.4)$$

This relation holds for any eigenfunction of $\hat{H}$ and for all linear combinations of the eigenfunctions, *that is*, for any function in the linear vector space L . Therefore, the following operator relation may be written:

$$\hat{g}\hat{H} = \hat{H}\hat{g}, \quad \hat{D}(g)\hat{H} = \hat{H}\hat{D}(g), \quad g \in G \quad (3.5)$$

This expresses in mathematical form the symmetry properties of the Hamiltonian of a quantum mechanical system.

We choose in the space L a symmetry-adapted basis $\varphi_{i\mu}^\alpha(\mathbf{r})$, where the index $i = 1, 2, \dots, n$ labels the basis functions of the irrep α and the index μ distinguishes independent basis functions of equivalent irreps. The matrices of the operators $\hat{D}(g)$ have in this basis a quasidiagonal structure

$$D_{i\alpha\mu; j\beta\nu}(g) = D_{ij}^{(\alpha)}\delta_{\alpha\beta}\delta_{\mu\nu} \quad (3.6)$$

We write the operator relation (3.5) in the chosen basis using the quasidiagonal form (3.6) of matrices

$$\sum_{i'} H_{i\alpha\mu, i'\beta\nu} D_{i'j}^{(\beta)}(g) = \sum_{i'} D_{ii'}^{(\alpha)}(g) H_{i'\alpha\mu, j\beta\nu} \quad (3.7)$$

or

$$H_{\alpha\mu, \beta\nu} D^{(\beta)}(g) = D^{(\alpha)}(g) H_{\alpha\mu, \beta\nu} \quad (3.8)$$

where the notation $H_{\alpha\mu, \beta\nu}$ is introduced for matrices with matrix elements $(H_{\alpha\mu, \beta\nu})_{ii'} = H_{i\alpha\mu, i'\beta\nu}$.

In accordance with Schur's lemmas for irreducible representations,

$$H_{\alpha\mu, \beta\nu} = H_{\mu\nu}^{(\alpha)} E \text{ for } \beta = \alpha \quad (3.9)$$

and

$$H_{\alpha\mu, \beta\nu} = 0 \text{ for } \beta \neq \alpha \quad (3.10)$$

where E is an $n_\alpha \times n_\alpha$ unit matrix. Hence, in the symmetry-adapted basis, the matrix H of the Hamiltonian has quasidiagonal structure (Wigner's theorem)

$$H_{i\alpha\mu, j\beta\nu} = H_{\mu\nu}^{(\alpha)} \delta_{ij} \delta_{\alpha\beta} \quad (3.11)$$

The block $H^{(\alpha)}$ is composed of matrix elements

$$H_{\mu\nu}^{(\alpha)} = \int \left(\varphi_{i\mu}^\alpha(\mathbf{r}) \right)^* \hat{H} \varphi_{i\nu}^\alpha(\mathbf{r}) d\mathbf{r} \quad (3.12)$$

does not depend on the index $i = 1, 2, \dots, n_\alpha$, and is repeated n_α times in the matrix H of the Hamiltonian $\hat{H}$.

In the symmetry-adapted basis, the diagonalizing of the matrix H is reduced to the diagonalizing of its diagonal blocks. Every eigenvalue of the matrix $H^{(\alpha)}$ is repeated n_α times in the total list of the eigenvalues of the operator $\hat{H}$. From the above discussion it also follows that the eigenfunctions of the Hamiltonian $\hat{H}$ corresponding to the same eigenvalue are the basis functions of an irrep of the symmetry group G of $\hat{H}$ (in the absence of accidental degeneracy that is not due to the symmetry) and the degeneracies of eigenvalues are equal to dimensions of the irreps of G (also in the absence of accidental degeneracy). Thus, the eigenstates $\varphi(\mathbf{r})$ and their eigenvalues may be labeled by the irreps of the symmetry group G of the Hamiltonian $\hat{H}$.

The symmetry properties of molecular orbitals and the degeneracy of the corresponding eigenvalues are defined by the irreducible representations of the point groups. The tables of these irreps characters are published in many books [13, 25], and their notations are well known and, as a rule, unambiguous. The energy-level degeneracy is usually 1 (a, b irreps), 2 (e irreps), and 3 (t irreps). As an exclusion, the icosahedral point-symmetry group of the fullerene molecule C_{60} has four- and five-dimensional representations (g and h irreps, respectively). The first-principles LCAO calculations of the molecular systems are usually made directly without the application of the Wigner theorem; the symmetry of molecular orbitals is used mainly for their classification and interpretation of the results obtained. However, for a large number of basis functions, the diagonalizing of the matrix H becomes a difficult, time-consuming work. Use of a symmetry-adapted basis in such a case can be useful even for molecular systems.

For crystalline solids the translation symmetry of the Hamiltonian is taken into account in any electronic-structure calculations as it allows calculations to be made for the basis connected only with the primitive unit cell. In the translation-symmetry-adapted basis, the matrix H has a quasideagonal structure with identical blocks related to an irrep $\mathbf{k}$ of the translation-symmetry group T . As the latter is Abelian, its irreps are one-dimensional. The translation-symmetry-adapted functions are known as Bloch functions and numbered by wavevector $\mathbf{k}$. Use of the point symmetry of a crystal allows the number of Bloch functions calculated to be decreased and further block diagonalization of Hamiltonian of a crystal to be made.

The space symmetry of crystalline orbitals is defined by irreducible representations of space groups. As will be shown in the next sections, the structure of these irreps is more complicated than in the case of point groups. The dimensions of the space-group irreps and the corresponding degeneracy of energy levels are also different from those for point groups. In versions CRYSTASL-98,03,06 computer codes, the automatic full space-group symmetry adaptation of LCAO is included [26]. It is particularly efficient for crystals with high symmetry containing many atoms in the primitive unit cell, for example, a cubic crystal of pyrope with 80 atoms in the cell [27].

The time-reversal symmetry of the crystalline Hamiltonian introduces an additional energy-level degeneracy. Let the Hamiltonian operator $\hat{H}$ be real. The transition in the time-dependent Schrodinger equation to a complex-conjugate equation with simultaneous time-inversion substitution

$$i \frac{\partial \varphi(\mathbf{r}, t)}{\partial t} = \hat{H} \varphi(\mathbf{r}, t), \quad i \frac{\partial \varphi^*(\mathbf{r}, -t)}{\partial t} = \hat{H} \varphi^*(\mathbf{r}, -t) \quad (3.13)$$

shows that the functions $\varphi(\mathbf{r}, t)$ and $\varphi^*(\mathbf{r}, -t)$ are solutions of the same time-dependent Schrödinger equation. This combined operation (complex conjugation + time inversion) is called the time-reversal transformation. Applying this operation to the time-independent Schrödinger equation for the time-independent part of stationary-state wavefunctions

$$\hat{H} \varphi(\mathbf{r}) = E \varphi(\mathbf{r}), \quad \hat{H} \varphi^*(\mathbf{r}) = E \varphi^*(\mathbf{r}) \quad (3.14)$$

we see that $\varphi(\mathbf{r})$ and $\varphi^*(\mathbf{r})$ are the eigenfunctions of the same real operator $\hat{H}$ belonging to the same eigenvalue E . So with respect to the time-independent part of stationary states $\varphi(\mathbf{r})$, the time-reversal operator reduces to a simple complex conjugation

$$\hat{K} \varphi(\mathbf{r}) = \varphi^*(\mathbf{r}) \quad (3.15)$$

Let φ_i ($i = 1, 2, \dots, n$) be eigenfunctions of a real Hamiltonian $\hat{H}$ belonging to an eigenvalue E and also be the basis of a unitary irrep $D(g)$ of its symmetry group G ($g \in G$). The functions $\hat{K} \varphi_i = \varphi_i^*$ are also eigenfunctions of $\hat{H}$ belonging to the same eigenvalue E , but transforming according to the irrep $D^*(g)$ [13]. The irreps $D(g)$ and $D^*(g)$ may be either equivalent or inequivalent. The functions φ_i and φ_i^* may be linearly dependent or linearly independent. There are three cases: (1) the functions φ_i and φ_i^* are linearly dependent and are bases of equivalent irreps, (2) the functions φ_i and φ_i^* are linearly independent and transform according to inequivalent irreps, and (3) the functions φ_i and φ_i^* are linearly independent and are bases of equivalent irreps. In cases 2 and 3, the eigenvalue E belongs to $2n$ states φ_i and φ_i^* . They form a basis of the rep of the group G that is the sum of two irreps $D(g)$ and $D^*(g)$ of the same dimension n . Thus, the degeneracy of the eigenvalue E doubles with respect to that caused by the symmetry group in the space. In case 1, there is no additional degeneracy. In tables of irreps of space groups, the complex-conjugate irreps are usually united in one so-called physically irreducible rep. When analyzing the degeneracy of one-electron energy levels in crystals, it is necessary to take into account the time-reversal symmetry. In particular, even in the case when the point-symmetry group F of a crystal does not include inversion, the complex-conjugated crystalline orbitals with wavevectors $\mathbf{k}$ and $-\mathbf{k}$ correspond to the same energy eigenvalue.

3.1.2 Irreducible Representations of Translation Group: Brillouin Zone

The group T of pure translations t_a of an infinite lattice is a group of infinite order. By introducing cyclic boundary conditions, one assumes that the infinite crystal consists of equivalent blocks in the form of parallelepipeds having sides

$\mathbf{A}_1 = N_1 \mathbf{a}_1, \mathbf{A}_2 = N_2 \mathbf{a}_2, \mathbf{A}_3 = N_3 \mathbf{a}_3$. It is assumed that the points of different blocks connected by translations are physically equivalent, *that is*, $t_{\mathbf{A}_j}^{N_j} = t_0$. The large positive number $N = N_1 N_2 N_3$ defines the size of each block, also called the main region of a crystal (this block contains N primitive unit cells in the cyclic model of a crystal). Only the finite-order group $T^{(N)}$ (modulo translations $\mathbf{A}_1, \mathbf{A}_2, \mathbf{A}_3$) of N translations $\mathbf{a}_n = \sum_{i=1}^3 n_i \mathbf{a}_i$ inside the main region is considered when generating the irreps of the translation group. Because this group is Abelian, all its irreps are one-dimensional. Moreover, group $T^{(N)}$ is a direct product of groups $T^{(N_1)}, T^{(N_2)}$, and $T^{(N_3)}$, as all the translations $t_{\mathbf{a}_n}$ commute. Each group $T^{(N_i)}$ of N_i translations $t_{n_i \mathbf{a}_i}$ has N_i one-dimensional irreps $D^j(t_{n_i \mathbf{a}_i})$, $j = 1, 2, \dots, N_i$, satisfying the condition $[D^j(t_{\mathbf{a}_i})]^{N_i} = D^j(t_{N_i \mathbf{a}_i}) = D^j(t_0) = 1$. Taking $D^j(t_{\mathbf{a}_i}) = \exp(-2\pi i p_j / N_j)$ (where p_j is an integer), one satisfies this condition. The integer $p_j = 0, 1, \dots, N_j - 1$ ($i = 1, 2, 3$) denotes different irreps of the translation group $T^{(N_i)}$. The irrep $D^{(p_1 p_2 p_3)}(t_{\mathbf{a}_n})$ of the translation group $T^{(N)}$ can be written as

$$D^{(p_1 p_2 p_3)}(t_{\mathbf{a}_n}) = \exp[-2\pi i (p_1 n_1 / N_1 + p_2 n_2 / N_2 + p_3 n_3 / N_3)] \quad (3.16)$$

There are $N = N_1 N_2 N_3$ sets of integers p_1, p_2, p_3 ($p_i = 0, 1, \dots, N_i - 1$) that are used to label N different irreps of the translation group $T^{(N)}$.

Introducing the primitive translation vectors $\mathbf{B}_1, \mathbf{B}_2, \mathbf{B}_3$ of the reciprocal lattice by

$$(\mathbf{a}_i \cdot \mathbf{B}_j) = 2\pi \delta_{ij}, \quad (i, j = 1, 2, 3) \quad (3.17)$$

one may define allowed $\mathbf{k}$ -vectors (wavevectors) by $\mathbf{k} = \kappa_1 \mathbf{B}_1 + \kappa_2 \mathbf{B}_2 + \kappa_3 \mathbf{B}_3$, where $\kappa_i = p_i / N_i$ ($i = 1, 2, 3$). Thus,

$$(\mathbf{k} \cdot \mathbf{a}_n) = 2\pi (n_1 p_1 / N_1 + n_2 p_2 / N_2 + n_3 p_3 / N_3) \quad (3.18)$$

so that

$$D^{(\mathbf{k})}(t_{\mathbf{a}_n}) = \exp(-i \mathbf{k} \cdot \mathbf{a}_n) \quad (3.19)$$

The N irreps of $T^{(N)}$ are now labeled by the N allowed $\mathbf{k}$ -vectors. The point symmetry of reciprocal lattice coincides with that of the direct one. However, the type of reciprocal lattice may differ from that of the direct lattice.

Adding the reciprocal lattice vector

$$\mathbf{B}_m = \sum_i m_i \mathbf{B}_i \quad (3.20)$$

to the allowed $\mathbf{k}$ -vector, we have

$$\begin{aligned} \exp(-i(\mathbf{k} + \mathbf{B}_m) \cdot \mathbf{a}_n) &= \exp(-i \mathbf{k} \cdot \mathbf{a}_n) \exp(-i \mathbf{B}_m \cdot \mathbf{a}_n) \\ &= \exp(-i \mathbf{k} \cdot \mathbf{a}_n) \end{aligned} \quad (3.21)$$

A pair of vectors $\mathbf{k}$ and $\mathbf{k}' = \mathbf{k} + \mathbf{B}_m$ is said to be equivalent since the irrep of $T^{(N)}$ described by $\mathbf{k}$ can be equally well described by $\mathbf{k}'$. Therefore, the label $\mathbf{k}$ is determined up to within a reciprocal lattice vector and can be changed by vectors $\mathbf{B}_m$ of the reciprocal lattice.

The basis functions for the irreps of the translation group $T^{(N)}$ are known as Bloch functions $\varphi(\mathbf{k}, \mathbf{r})$ and may be written in the form

$$\varphi(\mathbf{k}, \mathbf{r}) = \exp(i\mathbf{k} \cdot \mathbf{r})U(\mathbf{k}, \mathbf{r}) \quad (3.22)$$

where $U(\mathbf{k}, \mathbf{r}) = U(\mathbf{k}, \mathbf{r} + \mathbf{a}_n)$. Indeed

$$\begin{aligned} t_n \varphi(\mathbf{k}, \mathbf{r}) &= \exp(-i\mathbf{k} \cdot \mathbf{a}_n) \exp(i\mathbf{k} \cdot \mathbf{r})U(\mathbf{k}, \mathbf{r} - \mathbf{a}_n) \\ &= \exp(-i\mathbf{k} \cdot \mathbf{a}_n) \varphi(\mathbf{k}, \mathbf{r}). \end{aligned} \quad (3.23)$$

The Bloch functions are also called the $\mathbf{k}$ -basis.

Applying a space-group operator $g \equiv t_v R (g \in G)$ to the Bloch function $\varphi(\mathbf{k}, \mathbf{r})$, we obtain a Bloch function $\tilde{\varphi}(\mathbf{k}, \mathbf{r})$. Indeed

$$\begin{aligned} t_{a_n} t_v R \varphi(\mathbf{k}, \mathbf{r}) &= t_v R t_{R^{-1} \mathbf{a}_n} \varphi(\mathbf{k}, \mathbf{r}) \\ &= \exp(-i\mathbf{k} \cdot R^{-1} \mathbf{a}_n) t_v R \varphi(\mathbf{k}, \mathbf{r}) \\ &= \exp(-iR\mathbf{k} \cdot \mathbf{a}_n) t_v R \varphi(\mathbf{k}, \mathbf{r}) \end{aligned} \quad (3.24)$$

that is,

$$t_v R \varphi(\mathbf{k}, \mathbf{r}) = \tilde{\varphi}(R\mathbf{k}, \mathbf{r}) \quad (3.25)$$

As follows from (3.21) from the point of view of determining all the irreducible representations of a space group, it is only necessary to consider the wavevectors in one unit cell of reciprocal space ($\mathbf{k}$ -space), and the unit cell that is chosen is referred to as the first Brillouin zone (BZ). For most space groups it is not a primitive unit cell in $\mathbf{k}$ -space. Instead, the unit cell of $\mathbf{k}$ -space is the Wigner–Seitz unit cell. The latter is defined as consisting of all those points of $\mathbf{k}$ -space that lie closer to $\mathbf{k} = \mathbf{0}$ than to any other reciprocal lattice point. Its boundaries are therefore the planes that are the perpendicular bisectors of the lines joining the point $\mathbf{k} = \mathbf{0}$ to the nearest and sometimes to the next-nearest reciprocal lattice nodes (the planes bisecting the line from $\mathbf{k} = \mathbf{0}$ to $\mathbf{k} = \mathbf{B}_m$ have the equation $\mathbf{k} \cdot \mathbf{B}_m = |\mathbf{B}_m|^2/2$). For some direct lattices (simple cubic, e.g., see Fig. 3.1), only nearest-neighbor reciprocal lattice points are involved in the construction of the Brillouin zone, but for others (face-centered cubic, e.g., see Fig. 3.2), next-nearest neighbors are involved as well.

The advantage of this choice is that the Wigner–Seitz unit cell manifests the point-group symmetry F^0 of the appropriate crystal system. The disadvantage is that for certain Bravais lattices the appearance of BZ may be different for different values of lattice parameters. For all Bravais lattices except those of extremely low symmetry, the advantage of this definition outweighs the disadvantage [17]. For monoclinic and triclinic space groups, the problem of drawing of Brillouin zones

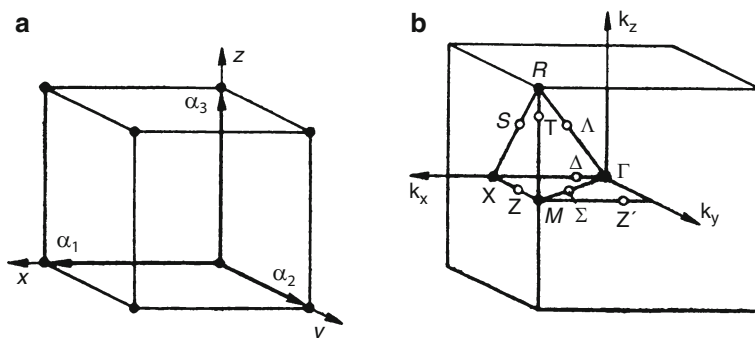


Fig. 3.1 Primitive unit cell and Brillouin zone for simple cubic lattice

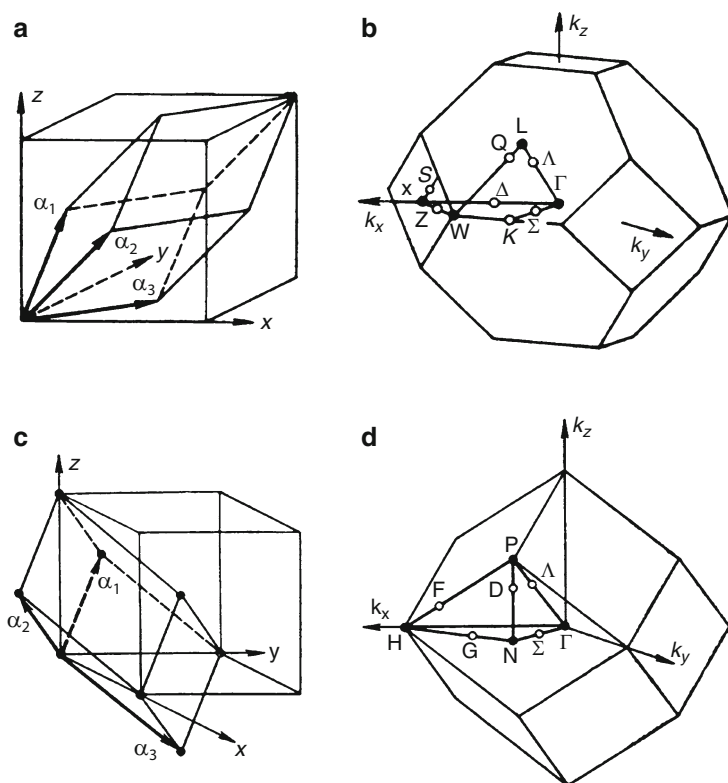
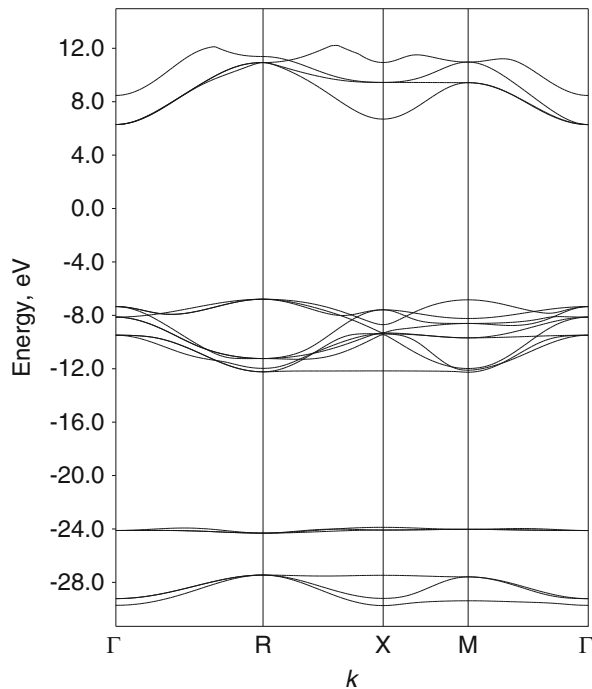


Fig. 3.2 Primitive unit cells (a, c) and Brillouin zones (b, d) for face-centered and body-centered cubic lattices

Fig. 3.3 Hartree–Fock energy bands for SrZrO_3 crystal



for all possible relative values of lattice parameters is so complicated that the primitive unit cell of the reciprocal lattice is used for the Brillouin zone. In [28] one can find Brillouin zones' representations for all the Bravais lattices and for each set of possible restrictions on the lattice parameters. For cubic, hexagonal, simple tetragonal, and simple orthorhombic lattices, the shape of the Brillouin zone is unique, while for trigonal, body-centered tetragonal, body-, base-, and face-centered orthorhombic lattices, there are two or more possible shapes depending on the relative lengths of the primitive translations and the angles between them.

By construction, the BZ contains N allowed $\mathbf{k}$ -vectors when N primitive unit cells are included in the main region of a crystal. As the number N is assumed to be arbitrarily large, in the limiting case of $N = \infty$, the allowed $\mathbf{k}$ -vectors take all values inside the BZ. In the electronic-structure calculations of crystals, finite (and relatively small) numbers of $\mathbf{k}$ -points are considered. However, the interpolation procedure used after calculation allows the one-electron energies to be shown as continuous functions of wavevectors (see, e.g., Figs. 3.3–3.5 for band structures of SrZrO_3 , MgO , and Si crystals, respectively).

Two vectors $\mathbf{k}$ and $\mathbf{k}'$ are said to be equivalent if $\mathbf{k}' = \mathbf{k} + \mathbf{B}_m$. By definition, no two interior points of a Brillouin zone can be equivalent; but every point on the surface of the Brillouin zone has at least one equivalent also on the surface of the Brillouin zone. For each BZ there is a basic domain Ω such that $\sum_R R\Omega$ is equal to the whole BZ, where R are the elements of the holosymmetric point group F^0

Fig. 3.4 Hartree–Fock energy bands for MgO crystal

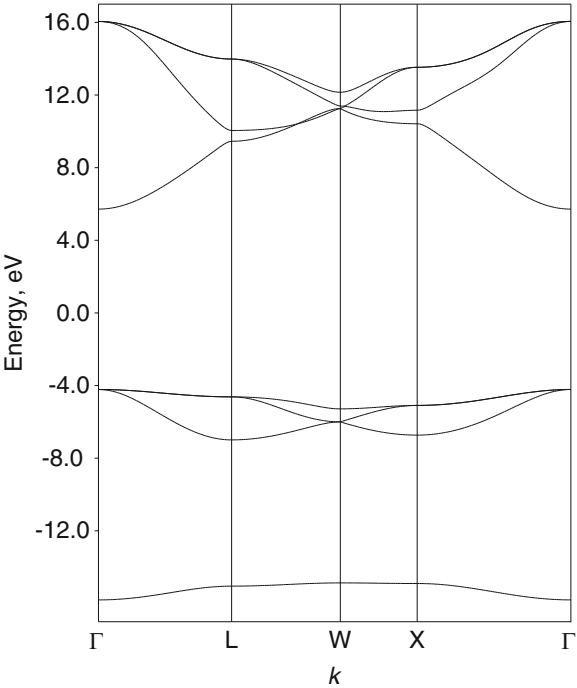
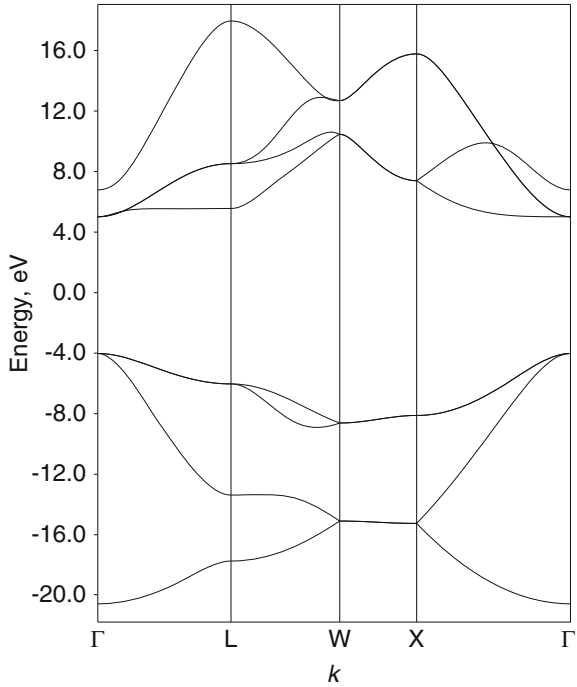


Fig. 3.5 Hartree–Fock energy bands for silicon crystal



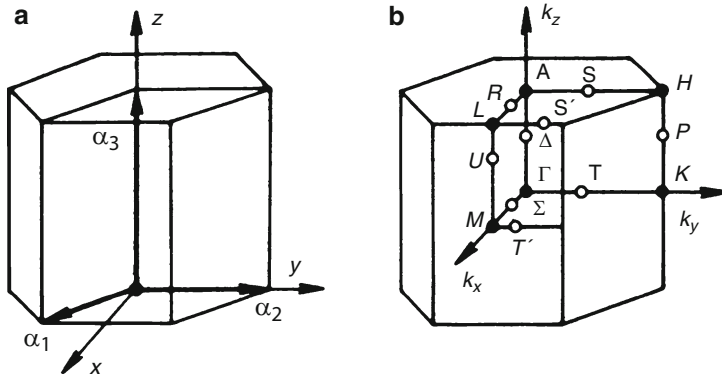


Fig. 3.6 Primitive unit cell and Brillouin zone for hexagonal lattice

(F^0 is the point-symmetry group of the Bravais lattice and defines the appropriate crystal system). For each space group there is a representation domain Φ of the appropriate BZ (it is also called the irreducible part of the Brillouin zone), such that $\sum_R R\Phi$ is equal to the whole BZ, where the sum over R runs through the elements of the point-symmetry group $F \subseteq F^0$ (F is also called the isogonal point group and is obtained by taking all the distinct elements R that are found in the elements $t_v R$ of space group G). For each holosymmetric space group (for which the set of all the distinct rotational parts of the space-group symmetry operations forms the holosymmetric point group F^0 of the appropriate crystal system), Φ can be taken to be identical with Ω . But for the remaining space groups, the volume of Φ is some small-integer multiple of the volume of Ω . This multiple is equal to n_{F^0}/n_F , that is, is defined by orders n_{F^0} and n_F of the holosymmetric point group n_{F^0} and crystal structure point group F . The majority of crystal structures considered in Sect. 2.3 have holosymmetric point groups. The exclusions refer to the structures of sphalerite and wurtzite with point groups T_d and C_{6v} being subgroups of cubic and hexagonal lattice point groups O_h and D_{6h} . In two cases under consideration (BZ for face-centered and hexagonal lattices, Figs. 3.2 and 3.6), the basic domain volumes are equal to 1/48 and 1/24 of the Brillouin-zone volume; the representation domains are two times larger.

Those elements of the point-symmetry group F^0 of the reciprocal lattice, which transform a point $\mathbf{k}$ into itself or into some equivalent $\mathbf{k}$ -point, form the wavevector point-symmetry group $F_k \subset F^0$. For example, for the direct face-centered cubic lattice ($F^0 = O_h$), BZ points $\Gamma(0,0,0)$, $X(1/2,1/2,0)$, $L(1/2,1/2,1/2)$, and $W(1/4,1/2,3/4)$ (see Fig. 3.2) have point-symmetry groups O_h , D_{4h} , D_{3d} , and D_{2d} , respectively. The point group F_k of the $\mathbf{k}$ -vectors F , Z , M , and A (Fig. 3.7) for a simple tetragonal lattice coincides with the D_{4h} point group of the tetragonal lattice itself; the point group D_{2h} of the $\mathbf{k}$ -vectors X and R is a subgroup of D_{4h} .

All the mentioned points of the BZ are called points of symmetry. By definition, $\mathbf{k}$ is a point of symmetry if there exists a neighborhood of $\mathbf{k}$ in which no point $\mathbf{k}'$

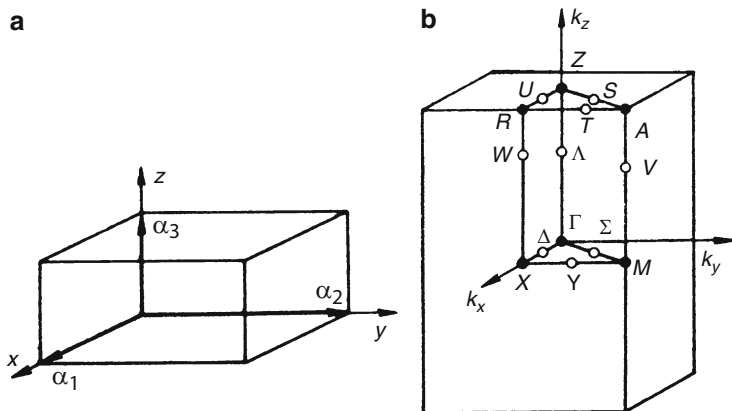


Fig. 3.7 Primitive unit cell and Brillouin zone for simple tetragonal lattice

has the same symmetry group F_k and $F_{k'} \subset F_k$. The Γ ($k = 0$) point of the Brillouin zone is usually a symmetry point; exceptions here are the space groups of the crystallographic classes C_s , C_{nv} , and C_n . All the other symmetry points are situated on the surface of the Brillouin zone and are usually denoted in a more or less unique way by Roman capital letters, as in Fig. 3.7, for a simple tetragonal lattice. Kovalev [29], however, used ordinal numbers to denote k -vectors.

If, in any sufficiently small neighborhood of k , there is a line (plane) of points passing through k and having the same point group F_k , then k is said to be on a line (plane) of symmetry. The lines of symmetry are denoted both by Roman (on the surface of the Brillouin zone) and Greek (inside the Brillouin zone) capital letters. A symmetry line may be denoted by two symmetry points at the ends of this line: $\Lambda - \Gamma L(C_{3v})$, $\Sigma - \Gamma M(C_{2v})$, $\Delta - \Gamma X(C_{2v})$ (Fig. 3.2a); the corresponding F_k groups are in parentheses. It is evident that the point groups C_{2v} of different wavevectors, being isomorphic to each other, do not coincide for all symmetry lines. For example, the second-order symmetry axis C_2 is along the X -coordinate axis for the ΓX line and along the XY symmetry axis for the ΓM line.

Tables 3.1–3.3 of k -vector types for BZ symmetry points and symmetry lines (space groups 221, 225, and 136) are taken from the site [16]. In fact, for all the space groups referring to the same crystal class and the same lattice type, the k -vector types are the same (groups 221–224 with simple cubic lattice, groups 225–228 with face-centered cubic lattice, and groups 123–138 for a simple tetragonal lattice). This follows from the fact that in reciprocal space only the point-symmetry operations R transform the k -vectors. In the space-group sets mentioned, the difference in symmetry operations appears only in the direct lattice where the improper translations are different. The columns labeled CDML and ITA in Tables 3.1–3.3 mean the k -points notations used in [17] (accepted in solid-state theory) and in [16] as Wyckoff positions of the reciprocal lattice space group. The latter notations are practically not used as the k -points labels. In the next section we discuss the generation of the space-group irreps from those of translation group.

Table 3.1 The $\mathbf{k}$ -vector types of group 221 [$\text{Pm}\bar{3}\text{m}$] (Table for arithmetic crystal class $\text{m}\bar{3}\text{mP}$, $\text{Pm}\bar{3}\text{m}-O_h^1$ (221) to $\text{Pn}\bar{3}\text{m}-O_h^4$ (224)). Reciprocal space group ($\text{Pm}\bar{3}\text{m}$)- O_h^1 (221)

k-vector label		Wyckoff position			Parameters
CDML		ITA			ITA
Γ	0, 0, 0	1	a	$\text{m}\bar{3}\text{m}$	0, 0, 0
R	1/2, 1/2, 1/2	1	b	$\text{m}\bar{3}\text{m}$	1/2, 1/2, 1/2
M	1/2, 1/2, 0	3	c	4/mm.m	1/2, 1/2, 0
X	0, 1/2, 0	3	d	4/mm.m	0, 1/2, 0
Δ	0, u, 0	6	e	4m.m	0, y, 0 : $0 < y < 1/2$
T	1/2, 1/2, u	6	f	4m.m	1/2, 1/2, z : $0 < z < 1/2$
Λ	u, u, u	8	g	.3m	x, x, x : $0 < x < 1/2$
Z	u, 1/2, 0	12	h	mm2..	x, 1/2, 0 : $0 < x < 1/2$
Σ	u, u, 0	12	i	m.m2	x, x, 0 : $0 < x < 1/2$
S	u, 1/2, u	12	j	m.m2	x, 1/2, x : $0 < x < 1/2$

Table 3.2 The $\mathbf{k}$ -vector types of group 225 [$\text{Fm}\bar{3}\text{m}$] (Table for arithmetic crystal class $\text{m}\bar{3}\text{mF}$, $\text{Fm}\bar{3}\text{m}-O_h^5$ (225) to $\text{Fd}\bar{3}\text{c}-O_h^8$ (228)). Reciprocal space group ($\text{Im}\bar{3}\text{m}$)- O_h^9 (229)

k-vector label		Wyckoff position			Parameters
CDML		ITA			ITA
Γ	0, 0, 0	2	a	$\text{m}\bar{3}\text{m}$	0, 0, 0
X	1/2, 0, 1/2	6	b	4/mm.m	0, 1/2, 0
L	1/2, 1/2, 1/2	8	c	. $\bar{3}\text{m}$	1/4, 1/4, 1/4
W	1/2, 1/4, 3/4	12	d	$\bar{4}\text{m}.2$	1/4, 1/2, 0
Δ	u, 0, u	12	e	4m.m	x, 0, 0 : $0 < x < 1/2$
Λ	u, u, u	16	f	.3m	x, x, x : $0 < x < 1/4$
V	1/2, u, 1/2 + u	24	g	mm2..	x, 1/2, 0 : $0 < x < 1/4$
Σ	u, u, 2u	24	h	m.m2	x, x, 0 : $0 < x < 3/8$
S	1/2 + u, 2u, 1/2 + u	24	h	m.m2	x, 1/2, x : $0 < x < 1/8$
$S \sim S_1[\text{KM}]$		24	h	m.m2	x, x, 0 : $3/8 < x < 1/2$
$\text{SM} + S_1[\text{GMM}]$		24	h	m.m2	x, x, 0 : $0 < x < 1/2$
Q	1/2, 1/4 + u, 3/4 - u	48	i	..2	1/4, 1/2 - y, y : $0 < y < 1/4$

3.1.3 Stars of Wave Vectors. Little Groups. Full Representations of Space Groups

The representation theory of space groups uses a theorem that the translation group T is an invariant subgroup of G ($T \triangleleft G$ see Sect. 2.1.2). Therefore, the little-group method [13] may be used for the generation of irreps of space group G from irreps of translation subgroup T . As was shown in Sect. 3.1.2, the one-dimensional

Table 3.3 The $\mathbf{k}$ -vector types of group 136 [P42/mnm] (Table for arithmetic crystal class 4/mmmP, P4/mmm- D_{4h}^1 (123) to P42/ncm- D_{4h}^{16} (138)). Reciprocal space group (P4/mmm)- D_{4h}^1 (123)

k-vector label		Wyckoff position				Parameters
CDML		ITA				ITA
Γ	0, 0, 0	1	a	4/mmm		0, 0, 0
Z	0, 0, 1/2	1	b	4/mmm		0, 0, 1/2
M	1/2, 1/2, 0	1	c	4/mmm		1/2, 1/2, 0
A	1/2, 1/2, 1/2	1	d	4/mmm		1/2, 1/2, 1/2
R	0, 1/2, 1/2	2	e	mmm.		0, 1/2, 1/2
X	0, 1/2, 0	2	f	mmm.		0, 1/2, 0
Λ	0, 0, u	2	g	4mm		0, 0, $z : 0 < z < 1/2$
V	1/2, 1/2, u	2	h	4mm		1/2, 1/2, $z : 0 < z < 1/2$
W	0, 1/2, u	4	i	2mm.		0, 1/2, $z : 0 < z < 1/2$
Σ	$u, u, 0$	4	j	m.2m		$x, x, 0 : 0 < x < 1/2$
S	$u, u, 1/2$	4	k	m.2m		$x, x, 1/2 : 0 < x < 1/2$
Δ	0, $u, 0$	4	l	m2m.		0, $y, 0 : 0 < y < 1/2$
U	0, $u, 1/2$	4	m	m2m.		0, $y, 1/2 : 0 < y < 1/2$
Y	$u, 1/2, 0$	4	n	m2m.		$x, 1/2, 0 : 0 < x < 1/2$
T	$u, 1/2, 1/2$	4	o	m2m.		$x, 1/2, 1/2 : 0 < x < 1/2$

irreps of translation group T transform under point-symmetry operations R of space group G according to relation (3.25), *that is*, the Bloch function with wavevector $\mathbf{k}$ transforms to a Bloch function with wavevector $R\mathbf{k}$.

Let us suppose that $D(g)$ is an irrep of G acting in a space L of dimension n . The operators $D(g)$ for $g = t_a \in T$ form a rep of T that is in general reducible. Let it contain irreps of T characterized by the vectors $\mathbf{k} = \mathbf{k}_1, \mathbf{k}_2, \dots, \mathbf{k}_n$. Therefore, a basis can be found in space L that consists of Bloch functions $\varphi(\mathbf{k}_1, \mathbf{r}), \dots, \varphi(\mathbf{k}_n, \mathbf{r})$. With respect to this basis, the elements of T are represented in the irrep $D(g)$ by diagonal matrices with elements $\exp(-i\mathbf{k}_p \mathbf{a})$, $p = 1, 2, \dots, n$. The fact that $D(g)$ is a rep of G implies that if we start with $\varphi(\mathbf{k}, \mathbf{r})$ and generate the Bloch functions $t_v R \varphi(\mathbf{k}, \mathbf{r}) = \tilde{\varphi}(R\mathbf{k}, \mathbf{r})$, where $t_v R \in G$, then we obtain some linear combination of n Bloch functions of the initial basis. This means that $R\mathbf{k}$ is one of the vectors $\mathbf{k}, \mathbf{k}_2, \dots, \mathbf{k}_n$.

In n -dimensional space L , there are no nonzero subspaces invariant with respect to $D(g)$ for all $g \in G$.

Therefore, as we run over all elements of G operating on $\varphi(\mathbf{k}, \mathbf{r})$ by $D(g)$, we generate the entire space L , *that is*, each of the vectors $\mathbf{k}_1, \dots, \mathbf{k}_n$ appears as the transform of $\mathbf{k}$ under some element of the point group F (point group of the space group G). It may be that the vectors $\mathbf{k}_1, \dots, \mathbf{k}_n$ are not all different. A set of n_s distinct (nonequivalent) $\mathbf{k}$ vectors chosen from the set $\mathbf{k}_1, \dots, \mathbf{k}_n$ is called the star

of wavevector $\mathbf{k}$ and is denoted as $^*\mathbf{k}$. A star can be generated from one of its members by operating on it by elements of point group F . The Γ point of BZ forms one-ray star for any space group as it is a coordinate system origin for all the point-symmetry group F transformations in reciprocal space. The stars $^*X$, $^*L$, and $^*W$ (see Fig. 3.2 of the Brillouin zone for the fcc direct lattice) consist of 3, 4, and 6 rays, respectively.

The point group of the wavevector $\mathbf{k}$ (little cogroup of $\mathbf{k}$) $F_{\mathbf{k}} \subseteq F$, by definition, consists of all the rotations or reflections $R\mathbf{k}$ ($i = 1, 2, \dots, n_{\mathbf{k}}$) that rotate $\mathbf{k}$ into itself or an equivalent vector $R\mathbf{k} = \mathbf{k} + \mathbf{B}_m$.

In Sect. 3.1.2 points and lines of symmetry in the Brillouin zone were defined for the case when $F = F^0$ (holosymmetric space groups, in particular O_h^5 and D_{4h}^{14}). In the same manner the points and lines of symmetry may be defined for the point group $F \subseteq F^0$. Then, instead of the basic domain of the Brillouin zone, the representation domain is introduced.

We can write F as a sum of left cosets with respect to the subgroup $F_{\mathbf{k}}$:

$$F = \sum_{i=1}^{n_s} R_i F_{\mathbf{k}} \quad (3.26)$$

where $n_s = n_F / n_{\mathbf{k}}$ is the number of $\mathbf{k}$ -vectors in the star $^*\mathbf{k}$. If $R_i \mathbf{k} = \mathbf{k}_i$, then all elements of the left coset $R_i F_{\mathbf{k}}$ transform $\mathbf{k}$ into $\mathbf{k}_i$.

By definition, the little group $G_{\mathbf{k}}$ of wavevector $\mathbf{k}$ consists of all elements $g_j^{\mathbf{k}} = t_{\mathbf{v}_j}^{(\mathbf{k})} + R_j^{(\mathbf{k})}$, $j = 1, 2, \dots, n_{\mathbf{k}}$, where $R_j^{(\mathbf{k})} \in F_{\mathbf{k}}$. The group $G_{\mathbf{k}} \subseteq G$ is a space group of order $N \cdot n_{\mathbf{k}}^j$ so that we can write G as a sum of left cosets with respect to the subgroup $G_{\mathbf{k}}$:

$$G = \sum_{j=1}^{n_s} g_j G_{\mathbf{k}}, \quad g_j = t_{\mathbf{v}_j} R_j \notin G_{\mathbf{k}} \quad (3.27)$$

Any element of coset $g_j G_{\mathbf{k}}$ transforms a Bloch function $\varphi(\mathbf{k}, \mathbf{r})$ into a Bloch function $\varphi(\mathbf{k}_j, \mathbf{r})$. Thus, if the vectors $\mathbf{k}, \mathbf{k}_2, \dots, \mathbf{k}_n$ characterizing the rep $D(g)$ of dimension $n = n_{\alpha} n_s$ are not all unique, then the star $\mathbf{k}, \mathbf{k}_2, \dots, \mathbf{k}_{n_s}$ is repeated exactly n_{α} times in the set $\mathbf{k}_1, \mathbf{k}_2, \dots, \mathbf{k}_n$.

Let the basis set of space $L^{(1)}$ be formed by Bloch functions $\varphi_i^{(\alpha)}(\mathbf{k}, \mathbf{r})$, ($i = 1, 2, \dots, n_{\alpha}$).

These functions form a basis of the so-called small (allowed) irrep of the space group $G_{\mathbf{k}}$:

$$D(g)\varphi_i^{(\alpha)}(\mathbf{k}, \mathbf{r}) = \sum_{i'=1}^{n_{\alpha}} D_{ii'}^{(\mathbf{k}, \alpha)}(g)\varphi_{i'}^{(\alpha)}(\mathbf{k}, \mathbf{r}), \quad g \in G_{\mathbf{k}} \quad (3.28)$$

The wavevector $\mathbf{k}$ is called a canonical wavevector.

Not all the irreps of space group $G_{\mathbf{k}}$ are small irreps of this group since the small irrep basis functions $\varphi_i^{(\alpha)}(\mathbf{k}, \mathbf{r})$, ($i = 1, 2, \dots, n_{\alpha}$) have an additional property: they are Bloch functions with the same vector $\mathbf{k}$, *that is*, the matrices of the

small irrep are diagonal for the pure translations t_a and have n_α equal diagonal elements $\exp(-i\mathbf{k}\mathbf{a})$. The Bloch functions $\varphi_i(\mathbf{k}_j, \mathbf{r}) = t_{\mathbf{v}_j} R_j \varphi_i(\mathbf{k}, \mathbf{r})$ form the basis set of irrep $\mathbf{k}_j = R_j \mathbf{k}$ of the translation group T . The space-group elements $g^{(\mathbf{k}_j)} = g_j g^{(\mathbf{k})} g_j^{-1}$ form the group $G_{\mathbf{k}}$ of the wavevector $\mathbf{k}_j$. The point group $F_{\mathbf{k}}^j$ consists of elements $R^{(\mathbf{k}_j)} = R_j R^{(\mathbf{k})} R_j^{-1}$. The basis functions $\varphi_i^{(\alpha)}(\mathbf{k}_j, \mathbf{r})$, ($i = 1, 2, \dots, n_\alpha$) of a space $L^{(j)}$ transform over the irrep $D^{(\mathbf{k}, \alpha)}(g_j^{-1} g^{(\mathbf{k}_j)} g_j)$

$$\begin{aligned} \hat{g}^{(\mathbf{k}_j)} \varphi_i(\mathbf{k}_j, \mathbf{r}) &= \hat{g}_j \hat{g}^{(\mathbf{k})} \varphi_i(\mathbf{k}, \mathbf{r}) = \sum_{i'} D_{ii'}^{(\mathbf{k}, \alpha)}(g^{(\mathbf{k})}) \varphi_{i'}(\mathbf{k}_j, \mathbf{r}) \\ &= \sum_{i'} D_{ii'}^{(\mathbf{k}, \alpha)}(g^{-1} g^{(\mathbf{k})} g_j) \varphi_{i'}(\mathbf{k}_j, \mathbf{r}) \end{aligned} \quad (3.29)$$

The space $L = \sum_j L^{(j)}$ of $n_s n_\alpha$ functions $\varphi_i(\mathbf{k}_j, \mathbf{r})$, ($i = 1, \dots, n_\alpha, j = 1, \dots, n_s$) is irreducible under G . These functions form a basis of the so-called full irrep $D^{(*\mathbf{k}, \alpha)}(g)$ of the space group. The full irrep $D^{(*\mathbf{k}, \alpha)}(g)$ of G is induced by the small irrep $D^{(\mathbf{k}, \alpha)}(g)$ of the little group $G_{\mathbf{k}} \subseteq G$: $D^{(*\mathbf{k}, \alpha)}(g) = D^{(\mathbf{k}, \alpha)}(g) \uparrow G$,

$$D_{i'j', ij}^{(*\mathbf{k}, \alpha)}(g) = D_{ii'}^{(\mathbf{k}, \alpha)}(g_{jj''}^{-1} g g_j) \delta_{j''j'} \quad (3.30)$$

The little group $G_{\mathbf{k}}$ is itself a space group. The small irreps of $G_{\mathbf{k}}$ can be found if projective irreps of the point group $F_{\mathbf{k}}$ are known.

3.1.4 Small Representations of a Little Group: Projective Representations of Point Groups

The small reps of little groups are sufficient for many purposes in solid-state theory, such as classifying states within electron energy bands and vibration frequencies within phonon band spectra, and for generating the symmetry-adapted wavefunctions.

The little group $G_{\mathbf{k}}$ is itself a space group. Whereas in the reps of G the translation t_a is represented by a diagonal matrix, in the small irreps $D^{(\mathbf{k}, \alpha)}$ of $G_{\mathbf{k}}$ that we are looking for, t_a is represented by a scalar matrix

$$D^{(\mathbf{k}, \alpha)}(t_a) = \exp(-i\mathbf{k} \cdot \mathbf{a}) E_{n_{k\alpha}} \quad (3.31)$$

where $n_{k\alpha}$ is the dimension of the small irrep $D^{(\mathbf{k}, \alpha)}$ and $E_{n_{k\alpha}}$ is the unit matrix of order $n_{k\alpha}$.

We decompose $G_{\mathbf{k}}$ into left cosets with respect to the translation group T :

$$G_{\mathbf{k}} = \sum_j g_j T, \quad g_j = t_{\mathbf{v}_j} R_j \quad (3.32)$$

The coset representatives in (3.32) obey the multiplication rule

$$t_{\mathbf{v}_i} R_i t_{\mathbf{v}_j} R_j = R_i R_j t_{\mathbf{v}_i + R_i \mathbf{v}_j} = t_{\mathbf{a}_{ij} + \mathbf{v}_s} R_s \quad (3.33)$$

where

$$t_{\mathbf{a}_{ij}} \in T \text{ and } \mathbf{a}_{ij} = \mathbf{v}_i + R_i \mathbf{v}_j - \mathbf{v}_i \quad (3.34)$$

Because $\mathbf{a}_{ij}$ is a translation, it follows that

$$D^{(\mathbf{k}, \alpha)}(g_i) D^{(\mathbf{k}, \alpha)}(g_j) = \exp(-i\mathbf{k} \cdot \mathbf{a}_{ij}) D^{(\mathbf{k}, \alpha)}(g_s) \quad (3.35)$$

If we now set for all $g \in G_k$

$$D^{(\mathbf{k}, \alpha)}(g) = \exp(-i\mathbf{k} \cdot \mathbf{v}) \tilde{D}^{(\mathbf{k}, \alpha)}(R) \quad (3.36)$$

then from (3.35) we obtain

$$\tilde{D}^{(\mathbf{k}, \alpha)}(R_i) \tilde{D}^{(\mathbf{k}, \alpha)}(R_j) = \exp(-i\mathbf{B}_i \cdot \mathbf{v}_j) \tilde{D}^{(\mathbf{k}, \alpha)}(R_s) \quad (3.37)$$

where the reciprocal lattice vector B_i is defined by the relation

$$R_i^{-1} \mathbf{k} = \mathbf{k} + \mathbf{B}_i \quad (3.38)$$

Equations (3.36) together imply that the matrices $\tilde{D}^{(\mathbf{k}, \alpha)}(R)$ are the same for all members of any fixed coset in (3.32), *that is*, these matrices are in correspondence with the elements of the factor group G_k/T . The factor group G_k/T is isomorphic with the little cogroup F_k so that $\tilde{D}^{(\mathbf{k}, \alpha)}$ is a matrix-valued function on the elements of the point group of wavevector $\mathbf{k}$ with the multiplication law

$$\tilde{D}^{(\mathbf{k}, \alpha)}(R_i) \tilde{D}^{(\mathbf{k}, \alpha)}(R_j) = \exp(-i\mathbf{B}_i \cdot \mathbf{v}_j) \tilde{D}^{(\mathbf{k}, \alpha)}(R_i R_j) \quad (3.39)$$

Matrices $\tilde{D}^{(\mathbf{k}, \alpha)}$ form a so-called projective rep of the point group F_k with the factor system

$$\omega(R_i, R_j) = \exp(-i\mathbf{B}_i \cdot \mathbf{v}_j) \quad (3.40)$$

where $\mathbf{B}_i$ is defined by (3.38).

We see from (3.36) that the small irreps $D^{(\mathbf{k}, \alpha)}$ of a little group are found if the projective irreps $\tilde{D}^{(\mathbf{k}, \alpha)}(R)$ of the point group F_k with the factor system (3.40) are known.

A factor system is specified by $n_{F_k}^2$ coefficients $\omega(R_i, R_j)$, where n_{F_k} is the order of the point group of wavevector F_k . These coefficients must satisfy the following identities for any R_i, R_j , and R_k :

$$(R_i, R_j R_k)(R_j, R_k) = (R_i R_j, R_k)(R_i, R_j) \quad (3.41)$$

implied by the associative law of group multiplication $R_i(R_j R_k) = (R_i R_j)R_k$. However, conditions (3.41) do not define a factor system uniquely [25]. If $D(R)$ is a projective representation of the group belonging to the factor system $\omega(R_i, R_j)$, then any other representation $D'(R) = D(R)/u(R)$ where $u(R)$ is an arbitrary single-valued function on the group, $|u(R)| = 1$, also defines a projective representation of the group, but with factor system $\omega'(R_i, R_j) = \omega(R_i, R_j)u(R_i, R_j)/u(R_i)u(R_j)$. The factor systems $\omega(R_i, R_j)$ and $\omega'(R_i, R_j)$ representations satisfying (3.41) are said to be projectively equivalent or p -equivalent. The set of all p -equivalent factor systems is called a class of factor systems. Note that two different p -equivalent representations may belong to the same factor system. For this to occur it is necessary that $u(R_i)u(R_j) = u(R_i R_j)$, that is, function $u(R)$ defines some ordinary (with all $\omega(R_i, R_j) = 1$) one-dimensional representation of the group. The group may have several classes of factor systems. It can be shown [25] that if $\omega(R_i, R_j) = \omega(R_j, R_i)$ for any pair of commuting elements ($R_i R_j = R_j R_i$), the factor system $\omega(R_i, R_j)$ is p -equivalent to identity factor system $\omega(R_i, R_j) = 1$ and the corresponding representation is p -equivalent to ordinary representation. Although the total number of possible factor systems is infinite, it can be shown that for a finite group the number of classes K of factor systems is finite [25]. For every group there is class K_0 with all $\omega(R_i, R_j) = 1$, which is called vector or ordinary representation. The other representations of the class K_0 with $\omega(R_i, R_j) \neq 1$ are projectively equivalent to vector representations. The dimensions of all p -equivalent representations are the same; the factor systems may differ. If a group has several classes of factor systems, then only the class K_0 may correspond to one-dimensional representations, and there will be no one-dimensional representations for classes $K_0 \neq K_p$.

Projective representations were first introduced by Shur [30], who developed a general theory of projective representations and worked out methods for constructing projective representations of finite groups. The connection between projective representations of point groups and representations of space groups was demonstrated by Lyubarskii, Kovalev, and Bir [25, 29, 31]. To find $D^{(k, \alpha)}$ with the factor system (3.40), Herring's approach [32] may be useful. In this approach the problem is reduced to finding ordinary irreps of abstract groups with order greater than that of F_k but not very large.

In [28] it is shown that these groups for different wavevectors in the Brillouin zone of one space group or for the same wavevector in the Brillouin zone of different space groups may be isomorphic. In [28] all the irreps of all the abstract groups that occur among reps of space groups are completely identified. In [17] the small irreps of little groups are found from those of the translation group by successive augmentations, each augmenting operator being chosen so that the augmented group contains the unaugmented one as an invariant subgroup.

The classes of all factor systems and the corresponding projective representation characters can be found in [25] for all 32 crystallographic point groups. Ten groups ($C_1, S_2, C_s, C_2, S_4, C_4, C_3, S_6, C_6, C_{3h}$) are cyclic, only one factor system K_0 belongs to these groups, that is, for these groups all the projective representations are p -equivalent to ordinary representations.

This short description of projective representations of point groups allows us to understand information given in different tables and on the site [16]. When using different existing tables for small representations of little groups, one has to remember that the projective representations of point groups can be ordered in different ways and may appear to be p -equivalent to each other.

When the space group G is symmorphic, all the fractional translations $\mathbf{v}_i$ may be chosen to be zero (Sect. 3.3) so that all the factors $\omega(R_i, R_j) = 1$ and $\tilde{D}^{k,\alpha}(R_i)$ coincide with the α th irrep of the point group F_k . When $\mathbf{k}$ is an interior point of the Brillouin zone, $(R_i^{-1}\mathbf{k} - \mathbf{k}) = 0$ for all R_i in the group F_k . It can also be that at some points of the Brillouin zone on its surface, $(R_i^{-1}\mathbf{k} - \mathbf{k})\mathbf{v}_j = 0$ for all R_i and $\mathbf{v}_j$ in the group G_k . In both these cases the projective irreps $D^{k,\alpha}(R)$ also coincide with the usual irreps of the point group of a wavevector. However, for some points on the surface of the Brillouin zone in the case of nonsymmorphic space groups, the projective irreps $D^{k,\alpha}(R)$ are not the usual irreps of the point group F_k .

As an example, we consider nonsymmorphic space group O_h^7 —the symmetry group of diamond structure. The Brillouin zone for the face-centered-cubic lattice and the symmetry points and the symmetry directions are shown in Fig. 3.2. The small representations of little groups G_Γ and G_L are p -equivalent to the ordinary irreducible representations of the corresponding wavevector point groups O_h and D_{3d} . For the Γ point it is evident as this point is inside (at the center) of the Brillouin zone. For the L point it can be easily shown. Indeed the point group of $L(1/2, 1/2, 1/2)$ consists of rotations C_{31} , C_{31}^{-1} through one of four third-order rotation axes and three rotations through second-order axes U_{xy}^- , U_{yz}^- , and U_{xz}^- (these operations and identity operation form point group D_3). All the remaining operations of the D_{3d} point group are obtained from relation $D_{3d} = D_3 \times C_i$ (direct product of D_3 and inversion group C_i). As can be seen from [16], these point-symmetry operations are included in space group O_h^7 (origin choice 2) with proper translations so that for any two elements R_i and R_j of point group D_{3d} , the multipliers $\omega(R_i, R_j) = 1$. For X and W points, the small representations are not p -equivalent to ordinary representations of wavevector point groups D_{4h} and D_{2d} , respectively. To show this, it is enough to find in the corresponding little cgroups at least one pair of commuting elements for which $\omega(R_i, R_j) \neq \omega(R_j, R_i)$. The point group $D_{4h} = D_4 \times C_i$ of $X(1/2, 1/2, 0)$ includes rotations C_{4z} , C_{2z} , and C_{4z}^{-1} through fourth-order z axis, rotations C_{2x} and C_{2y} through x - and y -coordinate axes, and rotations U_{x-y} , U_{xy} through second-order axes. The space group O_h^7 includes commuting elements C_{2y} and $IC_{2y} = \sigma_y$ with improper translations $(1/4, 1/2, 3/4)$ and $(1/2, 3/4, 1/4)$, respectively, given in basic translation vectors $\mathbf{a}_1, \mathbf{a}_2, \mathbf{a}_3$ (see [16, 19]). For the transformation C_{2y} and $\mathbf{k} = X$, we have $C_{2y}\mathbf{k} - \mathbf{k} = \mathbf{b}_1 + \mathbf{b}_2$ (sum of two basic reciprocal lattice vectors), for the transformation $IC_{2y} = \sigma_y$ we have $\sigma_y\mathbf{k} - \mathbf{k} = 0$. Therefore, $\omega(C_{2y}, \sigma_y) = \exp(i\pi/2) = i$, and $\omega(\sigma_y, C_{2y}) = 1$. Considering the commuting elements C_{2y} and $\sigma_x = IC_{2x}$ from point group D_{2d} of wavevector W , it is easy to show that $\omega(C_{2y}, \sigma_x) = -i$ and $\omega(\sigma_x, C_{2y}) = i$. In Table 3.4 for space group O_h^7 labels of the corresponding projective irreducible representations of point groups F_X and F_W and their dimensions are given. The point-symmetry group F_Z of the

Table 3.4 Characters of projective representations of point groups D_{4h} and D_{2d} for X and W points (space group O_h^7)

	E	C_{2x}	C_{2y}	C_{2z}	S_{4z}	S_{4z}^{-1}	σ_{x-y}	σ_{xy}	I	σ_x	σ_y	σ_z	C_{4z}^{-1}	C_{4z}	U_{x-y}	U_{xy}
X_1	2	0	0	2	0	0	2	2	0	0	0	0	0	0	0	0
X_2	2	0	0	2	0	0	-2	-2	0	0	0	0	0	0	0	0
X_3	2	0	0	-2	0	0	0	0	0	0	0	0	0	0	2	-2
X_4	2	0	0	-2	0	0	0	0	0	0	0	0	0	0	-2	2
	E	C_{2y}	S_{4y}	S_{4y}^{-1}	σ_x	σ_z	U_{x-z}	U_{xz}								
W_1	2	0	$1-i$	$1+i$	0	0	0	0								
W_2	2	0	$-1+i$	$-1-i$	0	0	0	0								
XW_1	2	0					0	0								

symmetry direction XW (12 rays in the star) on the surface of the Brillouin zone (see Fig. 3.2) consists of elements being common for both point groups F_X and F_W : $E, C_{2y}, \sigma_x, \sigma_z$. It was seen that $\omega(C_{2y}, \sigma_x) \neq \omega(\sigma_x, C_{2y})$ so that the only wavevector point group C_{2v} two-dimensional irreducible representation is not p -equivalent to any of the four ordinary one-dimensional representations of point group C_{2v} (see Table 3.4). The numbering of some small representations of space groups is different in different tables. For example, four small two-dimensional representations at the X point are ordered in different ways on the site [16] and in tables [17]. The ray of stars L, X , and W chosen for the small-representation generation can also be different, as can the origin choice for space-group description. All these differences do not change the full representations of space groups.

The dimension of a space-group full representation (degeneracy of energy levels in a crystal) for a given $\mathbf{k}$ is equal to the product of the number of rays in the star $\mathbf{k}^*$ and the dimension of the point group $F_{\mathbf{k}}$ irreducible representation (ordinary or projective). In particular, for the space group under consideration at the X point, the dimensions of full representations are 6 and at the W point—12. As to each of the degenerated states corresponds the same one-electron energy, it is enough to identify energy levels only for one ray of the wavevector star as it is made in the figures showing the electronic band structure. The degeneracy of levels at the symmetry points of the BZ is defined by the dimensions of wavevector point-group representations (ordinary or projective). To identify the one-electron energies at the symmetry lines, the compatibility relations are used. In Sect. 3.2.6 we discuss the band structure of some crystals using the considered information.

When the space group is realized in a crystalline structure, the atomic states included in the LCAO basis define the symmetry of crystalline orbitals appearing in the electronic-structure calculations. The symmetry connection of atomic and crystalline orbitals is given by induced representations of space groups considered in the next subsection.

3.2 Site Symmetry and Induced Representations of Space Groups

3.2.1 Induced Representations of Point Groups: Localized Molecular Orbitals

In the previous section we examined the use of space-group irreducible representations for the classification of the delocalized (Bloch-type) crystalline states. In this traditional approach the crystal is considered as a whole system, and the symmetry properties of the environment of constituent atoms are ignored. This results in a loss of information about the connection between the atomic and crystalline states. This information is widely used in the quantum chemistry of solids as it allows the crystalline properties to be explained from the knowledge of the chemical nature of the constituent atoms and their interactions. In the plane-waves methods of electronic-structure calculations, the Bloch-type delocalized states are not directly connected with the states of the separate atoms. However, in the LCAO methods the Bloch-type delocalized functions are represented as the linear combination of the functions of separate atoms. Therefore, the symmetry connection between the delocalized Bloch and localized atomic states appears to be important. If we use not only the space symmetry of a crystal as a whole but also the site symmetry of different groups of constituent atoms, we can considerably extend the possibilities of the group-theory applications. To study this in more detail, the reader is referred to our previous book [13] where we examined the theory and the applications of the site-symmetry approach to the electron, phonon, and magnetic properties of crystals and in the theory of phase transitions. In this section, we examine only those theoretical aspects of the site-symmetry approach that concern the electron states and allow analysis of the symmetry connection between the delocalized Bloch-type and localized Wannier-type electron states in crystals. We begin from the short description of the site (local)-symmetry approach in molecular quantum chemistry.

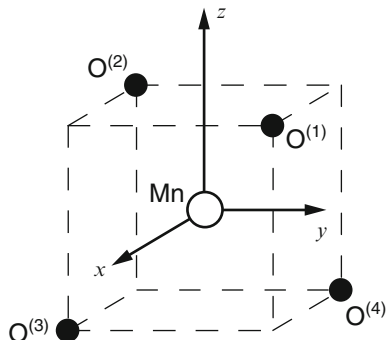
In the molecular systems with the point-symmetry group G , the site-symmetry subgroup H_q includes those symmetry operations that keep the point q fixed: $hq = q$. As an example, we consider a tetrahedral molecular ion $[\text{MnO}_4]^-$ (see Fig. 3.8). The Mn atom site-symmetry group coincides with the whole symmetry group T_d . The site-symmetry group of any of the four oxygens is $C_{3v} \subset T_d$.

Let $\hat{D}(g)$ be a rep of a group G ($g \in G$). A set of operators $\hat{D}(h)$ ($h \in H \subset G$) is a rep of H subduced by rep $\hat{D}(g)$ of G . The subduced irrep is denoted as $\hat{D} \downarrow H$. Even if $\hat{D}(g) = \hat{D}^{(\alpha)}(g)$, $g \in G$ is an irrep of G , the subduced rep is, in general, reducible and may be decomposed into irreps $d^{(\gamma)}$ of H :

$$D^{(\alpha)} \downarrow H = \sum_{\gamma} r_{\gamma}^{(\alpha)} d^{(\gamma)}(h) \quad (3.42)$$

The multiplicities are equal to

$$r_{\gamma}^{(\alpha)} = n_H^{-1} \sum_h \chi^{(\alpha)}(h) [X^{(\gamma)}(h)]^* \quad (3.43)$$

Fig. 3.8 MnO_4^- ion**Table 3.5** Correlation table for the point group T_d

T_d	C_{2v}	C_{3v}
a_1	a_1	a_1
a_2	a_2	a_2
e	$a_1 a_2$	e
t_1	$a_2 b_1 b_2$	$a_2 e$
t_2	$a_1 b_1 b_2$	$a_1 e$

where $\chi^{(\alpha)}(h)$ and $\chi^{(\gamma)}(h)$ are the characters of irreps $D^\alpha(h)$ and $d^{(\gamma)}(h)$ of the groups G and $H \subset G$, respectively.

Subducing the irreps of the group G with respect to its subgroup H and decomposing the subduced rep over the irreps of a subgroup, one obtains a correlation table. The rows of this table are labeled by irreps of a group G ; the columns denote different subgroups H of this group G . The frequencies of subduction by each irrep of G for the irreps of these subgroups are listed in the body of the table. One also has to take into account the possibility of different orientations of isomorphic subgroups with respect to the group G .

As an example we consider the correlation table for the point group T_d (Table 3.5).

The subduction of the subgroup irreps by the group irrep can be considered as the reciprocal operation to the induction of the group reps by the irreps of the subgroup H . Let group G be decomposed into left cosets with respect to H

$$G = \sum_{j''}^t g_{j''} H, \quad g_1 = E, \quad t = n_G/n_H \quad (3.44)$$

and L be a basis space of some rep of a group G . It is also a rep of its subgroup H . Let $L^{(1)}$ be a subspace of L with the basis $e_{i1}^{(\gamma)}$, $(i = 1, 2, \dots, n_\gamma)$ transforming according to an irrep $d^\gamma(h)$ of H :

$$D(h)e_{i1}^{(\gamma)} = \sum_{i'} d_{ii'}^\gamma(h) e_{i'1}^{(\gamma)}, \quad i = 1, 2, \dots, n_\gamma \quad (3.45)$$

Table 3.6 Induced irreps of the point group T_d

C_{2v}	T_d	C_{3v}	T_d
a_1	$a_1 e t_2$	a_1	$a_1 t_2$
a_2	$a_2 e t_1$	a_1	$a_2 t_1$
b_1	$t_1 t_2$	e	$e t_1 t_2$
b_2	$t_1 t_2$		

To express the invariance of $L^{(1)}$ under $\hat{D}(h)$ ($h \in H$) independently of a particular choice of basis, we write

$$\hat{D}(h)L^{(1)} = L^{(1)} \quad (3.46)$$

The linearly independent basis set

$$e_{ij}^{(\gamma)} = \hat{D}(g_j)e_{i1}^{(\gamma)}, \quad j = 1, \dots, t; \quad i = 1, 2, \dots, n_\gamma \quad (3.47)$$

spans a space $L^{(n)}$ of the dimension $n = t \cdot n_\gamma$. This space is invariant under the operators $\hat{D}(g)$, $g \in G$ and is defined as the space of the group G induced by the irrep $d^{(\gamma)}$ of its subgroup H and is written as $d^{(\gamma)} \uparrow G$. The matrices $D^{[\gamma]}(g)$ of the induced rep $d^{(\gamma)} \uparrow G$ have a block structure. Nonzero blocks are matrices of the irrep $d^{(\gamma)}$ of H . Every row and every column of $D^{[\gamma]}(g)$ has only one nonzero block. In the general case, a rep $d^{(\gamma)} \uparrow G$ is reducible

$$d^{(\gamma)} \uparrow G = \sum_{\alpha} r_{\alpha}^{[\gamma]} D^{(\alpha)}(g) \quad (3.48)$$

The Frobenius reciprocity theorem is proved [13]: the multiplicity of an irrep $D^{(\alpha)}(g)$ of G in a rep $d^{[\gamma]} \uparrow G$ induced by an irrep $d^{(\gamma)}$ of $H \subset G$ is equal to the multiplicity of an irrep $d^{(\gamma)}$ of H in the rep $D^{(\alpha)} \downarrow H$ subduced by $D^{(\alpha)}$ of H .

Using the Frobenius theorem, one can also write the reciprocal correlation table in which the irreps of the point group induced by irreps of its different point subgroups are given. Representations of the point group T_d induced by irreps of its point subgroups C_{2v} and C_{3v} are given in Table 3.6. The latter subgroup may be considered as the site-symmetry group of the oxygen atom in the molecular ion $(\text{MnO}_4)^-$.

The first and third columns in Table 3.6 contain the symbols of the point subgroups C_{2v} and C_{3v} and their irreps. The rest of the columns give the symbols of the induced representations of point group T_d decomposed over the irreps of this group.

The comparison of Tables 3.5 and 3.6 allows the Frobenius theorem to be checked. The tables of induced representations of the point groups are given in [13] and are the reciprocal correlation tables. The latter are given in [14]. In MO LCAO calculations, the canonical MO (delocalized over the whole space) are found. Their symmetry is defined by the irreps of the symmetry group of the whole molecule induced by the irreps of the site-symmetry groups of the constituent atoms. Use of

Table 3.7 Electronic structure of $(\text{MnO}_4)^-$

One-electron energies [eV]				Atomic contributions [%]				
State symmetry	SWX_α	CNDO	HF LCAO	$3d$	$4s$	$4p$	$2s$	$2p$
1	-9.28	-7.01	-7.62		–			100 (100)
$6a_1$	-10.53	-8.95	-8.03		8 (5)		4 (2)	88 (93)
$6t_2$	-10.37	-9.68	-9.06	3 (17)		7 (2)	2 (5)	88 (76)
$1e$	-12.24	-10.15	-11.48	29 (23)				72 (77)
$5t_2$	-12.43	-11.26	-12.82	53 (18)		2 (2)	6 (4)	39 (72)
$4t_2$	-24.30	-32.68	-29.44	7 (2)		4 (17)	87.5 (79)	15 (2)
$5a_1$	-24.65	-36.43	-30.01		7.5 (21)		91.5 (78)	– (1)

the induced representations of point groups allows the canonical MO to be divided into sets, to be connected with the localized MO (LMO), and to find the possible center of localization. In many cases this procedure can be done in several ways. Let us examine MO and LMO in the $(\text{MnO}_4)^-$ molecular ion. The $4s$ -, $4p$ -, and $3d$ -functions of the Mn atom span the space of the irreps a_1 , t_2 , $e + t_2$ of the molecular symmetry group T_d . The site-symmetry group of the O atom is C_{3v} . As follows from Table 3.6, the $2s$ and $2p_z$ -functions of the oxygen atom contribute to the canonical orbitals of a_1 and t_2 symmetry, and oxygen $2p_x$, $2p_y$ functions contribute to functions with the symmetries e , t_1 , t_2 . The site group C_{3v} may correspond to localized functions centered on oxygen atoms as well as on the Mn–O bond axis. The site group C_{2v} may be related to a two-centered O–O bond or to a three-centered O–Mn–O bond. The latter may also have C_s symmetry. Table 3.7 lists one-electron energies of the $(\text{MnO}_4)^-$ ion valence orbitals calculated by (a) the nonempirical MO LCAO method, (b) the SWX_α method, and (c) the semiempirical CNDO method (see Chap. 6). The weights of valence atomic orbitals in molecular orbitals are also given in cases (a) and (c) (in parentheses).

The valence canonical MO given in Table 3.7 may be distributed over sets according to their symmetry. There are three possible variants of distribution compatible with the symmetry requirements:

- 1) $C_{3v}(a_1) - 5a_1, 4t_2; C_{3v}(a_1) - 6a_1, 6t_2; C_{3v}(e) - 1e, 1t_1, 5t_2$
- 2) $C_{3v}(a_1) - 5a_1, 4t_2; C_{2v}(a_1) - 6a_1, 1e, 5t_2; C_{2v}(b_1) - 1t_1, 6t_2$ (3.49)
- 3) $C_{3v}(a_1) - 5a_1, 4t_2; C_s(a') - 6a_1, 1e, 5t_2, 6t_2, 1t_1$

The first variant is the most preferable as it corresponds to two-centered bonds, whereas the second and the third possibilities contain sets with bonds of more than two centers. The greater the number of centers participating in a bond, the less localized it seems to be. Table 3.7 shows that the sets $C_{3v}(a_1)$ correspond to orbitals localized near the oxygen atoms, the s -type is the lowest in energy, and the $2p_z$ -type (directed along the O–Mn line) is higher. The localized functions of symmetry contain a considerable admixture of Mn $3d$ states. So the center of localization is apparently displaced along the bond line toward the Mn atom.

Each of the three sets (3.49) contains states of t_2 symmetry, and in two sets there are states of a_1 symmetry. When generating localized orbitals, it is possible to take the linear combinations of initial canonical functions of the same symmetry and to vary the coefficients to get the orbitals with the best spatial localization. However, in the case of $(\text{MnO}_4)^-$, the orbitals $5a_1$ and $6a_1$ have considerably different energies. Therefore, the linear combinations must be used only for orbitals of t_2 symmetry (especially $5t_2$ and $6t_2$).

The analysis of the calculated one-electron states is often made only according to the weights of the atomic functions, and symmetry considerations are not taken into account. As a result, the $6t_2$, $6a_1$, and $1t_1$ states can be treated as being in the set corresponding to the localized functions of $2p$ -type centered on oxygen atoms. As follows from Table 3.7, these states do not span the space of the rep induced by some irrep of the site group of the oxygen atom. Therefore, it is impossible to generate any function localized on the oxygen atom. Hence, simply the analysis of the atomic orbital contributions in molecular states with close energies does not permit one to correctly relate the canonical orbitals to the localized ones.

As we can see, induced reps of point groups, in combination with an analysis of the atomic contributions in molecular eigenfunctions, are a good tool to find the regions of localization of electron density on atoms and bonds in a molecule. Of course the energy criterion must also be taken into consideration: a set is chosen so as to unite states with close energies.

Table 3.7 shows that the symmetry of localized orbitals does not depend in practice on the method of calculation of electronic structure. In particular, the method described here is equally applicable to the results of SWX_α calculations where the atomic basis is not used at all. The change in energy ordering of the $6a_1$ and $6t_2$ levels from that of the nonempirical method does not change the symmetry found for the localized orbitals.

The localized orbitals generation from the set of canonical MO allowed by symmetry requires additional choice of the localization criteria. The different orbital localization methods are implemented in molecular computer codes [33]. All of them are connected with the search for the coefficients connecting LMO with the canonical MO to satisfy the localization criteria.

The method due to Edmiston and Ruedenberg [34] works by maximizing the sum of the localized orbitals' two-electron self-repulsion integrals. The method requires the two-electron integrals transformed into the MO basis. Because only the orbitals to be localized are needed, the integral transformation is actually not very time consuming. However, the extension of this method to crystals is practically difficult as this requires the transformations of lattice sums of two-electron integrals.

The population method due to Pipek and Mezey [35] maximizes a certain sum of gross atomic Mulliken populations. The latter are not realistic when the LCAO basis includes diffuse atomic orbitals as is necessary for crystalline solids.

The most appropriate for the extension to crystal appears to be the Boys method. The Boys method [36] minimizes the sum of spreads of the localized orbitals $\phi_i(\mathbf{r})$

$$\min I = \sum_{i=1}^N [\langle \mathbf{r}^2 \rangle_i - \langle \mathbf{r} \rangle_i^2], \quad \left(\langle \mathbf{r}^m \rangle_i \equiv \int \mathbf{r}^m |\phi_i(\mathbf{r})|^2 d\mathbf{r} \right) \quad (3.50)$$

The summation in (3.50) is made over N occupied canonical MO found in LCAO self-consistent calculations.

$\sum_{i=1}^N \langle \mathbf{r}^2 \rangle_i$ is invariant with respect to any unitary transformation among functions ϕ_i :

$$\phi'_i = \sum_{i'}^N U_{i'i} \phi_{i'} \quad (3.51)$$

The minimum of the functional I corresponds to the maximum of the functionals:

$$\tilde{I} = \sum_{i=1}^N \langle \mathbf{r}^2 \rangle_i, \quad \text{or} \quad \tilde{\tilde{I}} = \sum_{i>j=1}^N [\langle \mathbf{r} \rangle_i - \langle \mathbf{r} \rangle_j]^2 \quad (3.52)$$

Thus, the Boys method can also be considered as maximization of the sum of distances between the orbital centroids $\tilde{\tilde{I}}$. The modifications of the Boys method are necessary to extend it for the localized crystalline orbitals generation. These modifications are considered in Sect. 3.3.

3.2.2 Induced Representations of Space Groups in $\mathbf{q}$ -Basis

Any subgroup rep can generate some induced rep of a group (see Sect. 3.2.1). In the particular case of a space group G , the small irreps of the little group $G_{\mathbf{k}} \subset G$ induce its full irreps.

In this and the next subsections, we consider induced reps of space groups generated by the irreps β of the site-symmetry subgroup $G_{\mathbf{q}}$ of point $\mathbf{q}$ in the direct lattice space ($\beta \uparrow G$). This type of induced rep of space groups was considered in [13]. In [37] a more general concept of band reps was introduced. All elements of the space group G can be written in the form $t_{\mathbf{v}_R + \mathbf{a}_n} R$, where $\mathbf{v}_R$ is a fractional lattice translation associated with the F point-group element R and $\mathbf{a}_n$ is a direct lattice translation vector.

The elements of the site-symmetry group $G_{\mathbf{q}} \subseteq G$ of the point $\mathbf{q}$ in the direct lattice space are those elements of G for which $g_{\mathbf{q}} \mathbf{q} = t_{\mathbf{v}_R + \mathbf{a}_n} R_{\mathbf{q}} \mathbf{q} = \mathbf{q}$. The space-group elements $g_{\mathbf{q}}$ are supposed to be given in the coordinate system whose origin

is at one of the Wyckoff positions. The site-symmetry group elements for the other Wyckoff positions are mapped by the space-group elements with the point-symmetry operators R . Thus, the site-symmetry group $G_{\mathbf{q}} \subseteq G$ is isomorphic with the point group $F_{\mathbf{q}}$ formed by $R_{\mathbf{q}}$. When the coordinate system origin is moved to the other Wyckoff position $\mathbf{q}_1$, the site-symmetry group elements of this new origin are elements of the point group $F_{\mathbf{q}_1}$, but the site-symmetry group elements $g_{\mathbf{q}}$ of the former origin $\mathbf{q}$ contain translations. As an example we consider the space group O_h^7 for the two origin choices given in the International Tables for Crystallography [19]. The site-symmetry group of Wyckoff position a(000) is mapped to the pure point-symmetry operations of the group for the first origin choice and to the set of operations with the translational part for the second origin choice.

Let the representatives $g_{jn} (j = 1, 2, \dots, n_q = n_G/n_F)$ in the decomposition

$$G = \sum_{j, \mathbf{n}} g_{jn} G_{\mathbf{q}}, \quad g_{jn} = t_{\mathbf{v}_j + \mathbf{a}_n} R_j \quad (3.53)$$

be chosen so that the points

$$\mathbf{q}_j = t_{\mathbf{v}_j} R_j \mathbf{q} \quad (3.54)$$

occupy the positions within the smallest unit cell (primitive or Wigner–Seitz). The operations g_{jn} generate from the point $\mathbf{q}$ sublattices $\mathbf{q}_j + \mathbf{a}_n (j = 1, 2, \dots, n_q)$.

Let the local functions $W_{i1}^{(\beta)}(\mathbf{r}) \equiv W_i(\mathbf{r} - \mathbf{q})$, ($i = 1, 2, \dots, n_\beta$) be centered at point $\mathbf{q}$ of the direct lattice and span the space of the irrep β of the site-symmetry group $G_{\mathbf{q}} \subset G$ with matrices $d^{(\beta)}(g_{\mathbf{q}})$ and characters $\chi^{(\beta)}(g_{\mathbf{q}}) (g_{\mathbf{q}} \in G_{\mathbf{q}})$. The nature of these functions depends on the physical problem under consideration. In the electron-band theory of crystals, $W_i^{(\beta)}(\mathbf{r} - \mathbf{q}_A)$ are atomic functions of atom A. In phonon spectroscopy applications, $W_i^{(\beta)}(\mathbf{r} - \mathbf{q}_A)$ mean the components of atomic displacements of an atom A; in magnetically ordered crystals, these functions are the magnetic moments of atoms [13]. Functions $W_{i1}^{(\beta)}(\mathbf{r})$ transform as

$$\begin{aligned} \hat{g}_{\mathbf{q}} W_{i1}^{(\beta)}(\mathbf{r}) &= W_i^{(\beta)}(R_{\mathbf{q}}^{-1}(\mathbf{r} - \mathbf{v}_{\mathbf{q}} - \mathbf{a}_n - R_{\mathbf{q}}\mathbf{q})) \\ &= W_i^{(\beta)}(R_{\mathbf{q}}^{-1}(\mathbf{r} - \mathbf{q})) = \sum_{i'=1}^{n_\beta} d_{i'i}^{(\beta)}(R_{\mathbf{q}}) W_{i'1}^{(\beta)}(\mathbf{r}) \end{aligned} \quad (3.55)$$

since the vector $\mathbf{q}$ remains invariant under the operations of the site group $G_{\mathbf{q}}$. All the functions $W_{i1}^{(\beta)}(\mathbf{r}) (i = 1, 2, \dots, n_\beta)$ are associated with the site $\mathbf{q}$.

The local functions associated with the smallest unit cell are obtained from local functions $W_{i1}^{(\beta)}(\mathbf{r})$ through

$$\begin{aligned} W_{ij}^{(\beta)}(\mathbf{r}) &= \hat{t}_{\mathbf{v}_j} R_j W_{i1}^{(\beta)}(\mathbf{r}) = W_i^{(\beta)}(R_j^{-1}(\mathbf{r} - \mathbf{q})), \\ i &= 1, 2, \dots, n_\beta; \quad j = 1, 2, \dots, n_q \end{aligned} \quad (3.56)$$

Functions in other unit cells are obtained through

$$W_{ij}^{(\beta)}(\mathbf{r} - \mathbf{a}_n) = \hat{t}_{\mathbf{a}_n} W_{ij}^{(\beta)}(\mathbf{r}) = W_{ij}^{(\beta)}(R_j^{-1}(\mathbf{r} - \mathbf{q}_j - \mathbf{a}_n)) \quad (3.57)$$

The local functions $W_{ij}^{(\beta)}(\mathbf{r} - \mathbf{a}_n)$ form the basis of an induced rep $\beta \uparrow G$ of space group G . Indeed, let the element $t_{\mathbf{v}_R} R$ transform the j th sublattice into the j' th one and be written in the form

$$t_{\mathbf{v}_R} R = t_{\mathbf{a}_{jj'}, t_{\mathbf{v}_{j'}}} R_{j'} t_{\mathbf{v}_q} R_q (t_{\mathbf{v}_j} R_j)^{-1} \quad (3.58)$$

where $R = R_{j'} R_q R_j^{-1}$ ($R_q \in F_q$) and $\mathbf{a}_{jj'}$ is the lattice vector. Equation (3.58) may be checked directly. From (4.2.6) we get for the local functions

$$t_{\mathbf{v}_R} R W_{ij}^{(\beta)}(\mathbf{r} - \mathbf{a}_n) = \sum_{i'} \left(R_{j'}^{-1} R R_j \right) W_{i'j'}^{(\beta)}(\mathbf{r} - R\mathbf{a}_n - \mathbf{a}_{j'j}) \quad (3.59)$$

The dimension of the rep $\beta \uparrow G$ is infinite for the model of an infinite crystal. In a cyclic model, the infinite crystal is replaced by a main region consisting of N smallest unit cells, and periodic boundary conditions are introduced. The total number of local functions $W_{ij}^{(\beta)}(\mathbf{r} - \mathbf{a}_n)$ becomes finite and equals $n_\beta n_{\mathbf{q}} N$ ($i = 1, 2, \dots, n_\beta, j = 1, 2, \dots, n_{\mathbf{q}}; n$ takes N values). These functions form an $n_\beta n_{\mathbf{q}} N$ -dimensional space of the rep of the space group G . This rep matrix consists of $n_\beta n_{\mathbf{q}}$ blocks arising from $d^{(\beta)}$.

To specify the induced rep $\beta \uparrow G$ in the basis of local functions $W_{ij}^{(\beta)}(\mathbf{r} - \mathbf{a}_n)$, one has to indicate the symmetry center $\mathbf{q}$ of local functions by its Wyckoff position and the irrep β of the site-symmetry point group $G_{\mathbf{q}}$. Thus, in the $\mathbf{q}$ -basis the induced rep $\beta \uparrow G$ is specified by the index $(\mathbf{q}, \beta)$.

As an example, we consider oxygen atom $2s$ -functions in the perovskite CaTiO_3 structure. The oxygen atoms occupy Wyckoff position c of the space group O_h^1 with the site-symmetry D_{4h} . The $2s$ -functions of an oxygen atom transform over a_{1g} irrep of the point group D_{4h} . Thus, the induced representation in $\mathbf{q}$ -basis (c, a_{1g}) is three-dimensional at each $\mathbf{k}$ point ($d^{(\beta)} = a_{1g}, n_\beta = 1, n_{\mathbf{q}} = 3$).

3.2.3 Induced Representations of Space Groups in k -Basis: Band Representations

In Sect. 3.1 we have considered the space-group irreps $D^{(k, \alpha)}(g)$ defined by stars $^* \mathbf{k}$ of wavevectors $\mathbf{k}$ from the first Brillouin zone and by irreps $D^{(\alpha)}$ of little groups $G_{\mathbf{k}}$. Let us construct in the space of induced rep $(\mathbf{q}, \beta)$ new basis functions that span the space of irreps of the translation group T (Bloch functions)

$$\Psi_{ij}^{(\beta)}(\mathbf{k}, \mathbf{r}) = \sum_n \exp(i\mathbf{k} \cdot \mathbf{a}_n) W_{ij}^{(\beta)}(\mathbf{r} - \mathbf{a}_n), \quad (i = 1, 2, \dots, n_\beta; j = 1, 2, \dots, n_{\mathbf{q}}) \quad (3.60)$$

and *vice versa*

$$\begin{aligned} W_{ij}^{(\beta)}(\mathbf{r} - \mathbf{a}_n) &= \frac{V_a}{(2\pi)^3} \int \exp(-i\mathbf{k}\mathbf{a}_n) \Psi_{ij}^{(\beta)}(\mathbf{k}, \mathbf{r}) d\mathbf{k} \\ W_{ij}^{(\beta)}(\mathbf{r} - \mathbf{a}_n) &= N^{-1} \sum_{\mathbf{k}} \exp(-i\mathbf{k}\mathbf{a}_n) \Psi_{ij}^{(\beta)}(\mathbf{k}, \mathbf{r}) \end{aligned} \quad (3.61)$$

for infinite and cyclic models of a crystal, respectively. Using (3.24), (3.28), and (3.59), one obtains

$$t_{v_R} R \Psi_{ij}^{(\beta)}(\mathbf{k}, \mathbf{r}) = \exp(-i\mathbf{R}\mathbf{k} \cdot \mathbf{a}_{jj'}) \sum_{i'} d_{i'i}^{(\beta)} \left(R_j^{-1} R R_j \right) \Psi_{i'j'}^{(\beta)}(\mathbf{R}\mathbf{k}, \mathbf{r}) \quad (3.62)$$

Let the wavevector $\mathbf{k}$ be fixed and $t_{v_R} R \in G_{\mathbf{k}}$. Then $p = n_{\beta} n_q$ functions $\Psi_{ij}^{(\beta)}(\mathbf{k}, \mathbf{r})$ span the space of the small representation of the little group $G_{\mathbf{k}}$ with the character

$$\chi_{\mathbf{k}}^{(\beta)}(g) = \sum_{j=1}^{n_q} \exp(-i\mathbf{k} \cdot \mathbf{a}_{jj'}) \tilde{\chi}^{(\beta)}(R_j^{-1} R R_j) \quad (3.63)$$

where

$$\tilde{\chi}^{(\beta)}(R_j^{-1} R R_j) = \begin{cases} 0, & \text{if } R_j^{-1} R R_j \neq R_q \\ \chi^{(\beta)}(R_q), & \text{if } R_j^{-1} R R_j = R_q \end{cases} \quad (3.64)$$

Knowing the characters (3.63) of the induced rep, one can easily calculate the number of times the small irrep $D^{(k,\gamma)}$ of the group $G_{\mathbf{k}}$ with characters $\chi^{(k,\gamma)}(g)$, $g \in G_{\mathbf{k}}$ is contained in the induced rep $(\mathbf{q}, \beta)$.

This procedure gives the labels of the induced rep $(\mathbf{q}, \beta)$ in the $\mathbf{k}$ -basis corresponding to those in the $\mathbf{q}$ -basis, *that is*, the results of the reduction of the induced rep over irreps of the group $G_{\mathbf{k}}$. All the information obtained can be specified by listing the symmetry (the labels of irreps) of the Bloch states with wavevectors $\mathbf{k}$ corresponding only to a relatively small number of $\mathbf{k}$ -points in the Brillouin zone forming a set K . The set K contains the inequivalent symmetry points of the Brillouin zone and one representative point from each inequivalent symmetry element (symmetry line or symmetry plane) if the latter does not contain the points of higher symmetry.

The symmetry properties of basis functions with other vectors $\mathbf{k}$ can be determined with the use of the compatibility relations.

The set K for the space groups with high-symmetry classes consists only of the symmetry points. For instance, the set K for the space groups O_h^5, O_h^7 contains the points Γ, X, L, W (Fig. 3.2) and for the space group O_h^4 , the points Γ, X, M, R (Fig. 3.2). The symmetry points can be absent in the Brillouin zone of space groups with low-symmetry classes.

The symmetry properties of basis functions of an induced rep are described by the full group irreps $(^*\mathbf{k}, \gamma)$ or by the small irreps $(\mathbf{k}, \gamma)$ of the wavevector groups $G_{\mathbf{k}}$

unambiguously related to them. Thus, as an index of an induced rep, we shall use the symbols of those small irreps of the little groups G_k with wavevectors from the set K that correspond to basis functions of a given induced rep

$$\mathbf{k}_1(\gamma_1^{(1)}, \gamma_2^{(1)}, \dots), \mathbf{k}_2(\gamma_1^{(2)}, \gamma_2^{(2)}, \dots), \dots, \mathbf{k}_i \in K \quad (3.65)$$

The index of the induced rep (3.65) can also be considered as the set of so-called subduction frequencies $r_{(*\mathbf{k}, \gamma)}^{(q, \beta)}$. The latter give the number of times the irrep $(*\mathbf{k}, \gamma)$ of G is contained in the induced rep (q, β) . From the Frobenius theorem the subduction frequencies $r_{(*\mathbf{k}, \gamma)}^{(q, \beta)}$ are equal to the number of times the irrep $(*\mathbf{k}, \gamma)$ subduces the irrep β of $G_k^{(*\mathbf{k}, \gamma)}$

$$r_{\beta}^{(*\mathbf{k}, \gamma)} = r_{(*\mathbf{k}, \gamma)}^{(q, \beta)} = \sum_{g \in G_q} (\chi^{(\beta)*}(g)) \chi^{(*\mathbf{k}, \gamma)}(g) \quad (3.66)$$

where $\chi^{(*\mathbf{k}, \gamma)}(g)$ and $\chi^{(\beta)}(g)$ are the characters of the irreps $(*\mathbf{k}, \gamma)$ of G and β of G_q , respectively.

To calculate the subduction frequencies (3.66), one may use different procedures [13]. The first uses (3.63) and does not require knowledge of the full irrep $(*\mathbf{k}, \gamma)$ characters. Indeed, one obtains, according to (3.63), the characters $\chi_k^{(\beta)}(g)$ of the rep of a little group G_k . Reducing this rep requires the characters of the irreps of the little group G_k (tabulated in [17] and on site [16]) and gives the induced rep index (3.66) in the $\mathbf{k}$ -basis. The second procedure for calculating subduction frequencies uses (3.66) and requires the character $\chi^{(*\mathbf{k}, \gamma)}$ of full irreps of space groups.

Comparing the two ways of finding the induced rep index in the $\mathbf{k}$ -basis, one may conclude:

1. The first one is more appropriate for q sets consisting of only one Wyckoff position in the unit cell (this is possible only in symmorphic space groups).
2. The second one is more appropriate for those wavevector stars that consist of one ray so that the full and small irreps coincide.

In [37] the concept of a band rep of a space group, which may be an induced rep, was introduced. Band reps were used to define the symmetry of an electron energy band as a whole entity.

From the group-theoretical point of view, a band rep of a space group is a direct sum of its irreps that have the following properties:

- (1) The space of the band rep contains the basis vectors with all the $\mathbf{k}$ -vector stars in the Brillouin zone.
- (2) The compatibility relations are fulfilled throughout the Brillouin zone in the model of an infinite crystal or for N points in the cyclic model.

It is obvious that at every $\mathbf{k}$ -point there is the same number p of Bloch-type basis states.

In a cyclic model of a crystal with N primitive cells in the main region, a band rep is an Np -dimensional reducible rep of a space group. An induced rep is a particular case of a band rep as it satisfies both properties 1 and 2 with $p = n_q n_\beta$ (n_β is the dimension of the site-symmetry group irrep for a point $\mathbf{q}$ belonging to the set of n_q points in the unit cell).

The index of a band rep in the $\mathbf{k}$ -basis has the form given by (3.65). By analogy with the same index for an induced rep, all information about the band rep can be given by specifying the symmetry (the labels of irreps) of the basis vectors with wavevectors $\mathbf{k} \in K$.

It is seen now that band reps (induced reps included) of space groups can be specified by the index (3.65) in the $\mathbf{k}$ -basis and only those band reps that are induced ones can also be specified in the $\mathbf{q}$ -basis in the form $(\mathbf{q}, \beta)$.

Let us return to our example of the induced representation (c, a_{1g}) of the space group O_h^1 formed by $2s$ -functions of oxygen atoms in the perovskite structure. Using the full group irreps from the site [16], we calculate the subduction frequencies (3.66) for belonging to K set points of Brillouin zone and write the induced band representation (c, a_{1g}) in the $\mathbf{k}$ -basis in the form $\Gamma(1^+3^+)\text{R}(5^+)\text{M}(4^+5^-)\text{X}(1^+3^-4^-)$. The labels of the small irreps of the little groups are taken from [17].

3.2.4 Simple and Composite Induced Representations

The use of the $\mathbf{q}$ -basis of induced reps allows one to introduce the concept of simple induced reps, which facilitates the analysis of all possible types of induced reps for a given space group. An induced rep is called simple if it is impossible to split up the space of this rep into subspaces that are invariant under operators $\hat{g}$ ($g \in G$) and are also the spaces of some induced reps.

By definition, a composite induced rep is a direct sum of the simple ones. As a group rep, a simple induced rep is reducible, so we prefer to avoid the expression “irreducible induced rep” used in [37]. The term introduced in [38], “elementary induced rep,” is equivalent to the term simple induced rep used in this book.

All simple induced reps may be generated by induction from the irreps of site-symmetry groups $G_{\mathbf{q}'}$ of a relatively small number of $\mathbf{q}'$ points forming the set Q in the Wigner–Seitz unit cell of the direct lattice. The set Q consists of

- (1) All the inequivalent symmetry points of the Wigner–Seitz unit cell.
- (2) One representative point from all the inequivalent symmetry lines and symmetry planes that do not contain the symmetry points.

The site groups $G_{\mathbf{q}}$ for all $\mathbf{q} \in Q$ are called maximal isotropy subgroups in [38]. The set Q in the Wigner–Seitz unit cell is determined in the same way as the set K in the Brillouin zone. However, the action of symmetry operations in the direct and reciprocal spaces is different.

A reducible rep $d(g) = \sum_{\beta} r_{\beta} d^{(\beta)}(g)$ of the site group G_q induces a composite induced rep that is the direct sum of reps induced by the irreps $d^{(\beta)}(g)$. As an example, we can consider a composite rep induced by d -functions of a transition metal atom (Wyckoff position a) in the perovskite structure: these functions span the reducible five-dimensional rep of the site-symmetry group O_h subducing t_{2g} and e_{2g} irreps. Therefore, the induced irrep in q -basis is composite: $b(e_g) + b(t_{2g})$.

Now let us show that if the q point does not belong to the set Q , the rep (q, β) induced from the irrep of the site group G_q is composite.

Let q' be one of the points in the set Q for which the site group $G_{q'}$ contains G_q as a subgroup ($G_q \subset G_{q'}$).

This condition may be satisfied for several points q' of the set Q . The decomposition of the site group $G_{q'}$ into left cosets with respect to the subgroup G_q has the form

$$G_{q'} = \sum_{j=1}^n t_{v_j} R_j G_q \quad (3.67)$$

If the functions $W_{i1}^{(\beta)}(\mathbf{r}) (i = 1, 2, \dots, n_{\beta})$ span the space of an irrep β of the group G_q , then $n \cdot n_{\beta}$ functions

$$W_{ij}^{(\beta)}(\mathbf{r}) = t_{v_j} R_j W_{i1}^{(\beta)}(\mathbf{r}) \quad (3.68)$$

form the space of the site group G_q rep $\beta \uparrow G_q$ induced from the irrep β of its subgroup $G_{q'}$. Let us decompose the rep $\beta \uparrow G_{q'}$ into the irreps α' of the group $G_{q'}$

$$\beta \uparrow G_{q'} = \sum_{\alpha'} r_{\alpha'} \alpha' \quad (3.69)$$

The irrep β of the group $G_{q'}$ and rep $\beta \uparrow G_{q'}$ of the group $G_{q'}$ generate the same induced rep

$$(q, \beta) = (q', \beta \uparrow G_{q'}) = \sum_{\alpha'} r_{\alpha'} (q', \alpha') \quad (3.70)$$

which is obviously composite. Thus, we have proved that all the possible simple induced reps of a given space group G may be generated by induction from the irreps of the subgroups $G_{q'}$ for $q' \in Q$.

In [38] a complete classification of the inequivalent simple induced reps is given and all the cases when the reps induced from the irreps of maximal isotropy subgroups can be equivalent to one another are considered. First, equivalent induced reps at the same site $q' \in Q$ arise.

1. By induction from one-dimensional irreps forming an orbit of the normalizer $N_G(G_{q'})$, there are 23 pairs of them belonging to 15 space groups.
2. Four types of isotropy subgroups (C_{2v} , D_2 , D_{2h} , T) may generate reps induced by irreps that do not form an orbit of $N_G(G_{q'})$. There are 34 pairs of them belonging to 25 space groups.

Second, there are 17 pairs of different maximal isotropy subgroups (belonging to 14 space groups) yielding 63 pairs of equivalent induced reps by induction from one-dimensional irreps. When inducing from two-dimensional irreps of isotropy subgroups, 33 pairs of equivalent induced reps are obtained, belonging to 23 space groups. In total, there are 153 pairs of equivalent induced reps (57 at the same site and 96 at different sites) induced from different irreps of maximal isotropy subgroups. In [38] it was also shown that 40 reps belonging to 25 space groups and induced from irreps of maximal isotropy groups are composite.

There is a formal analogy between simple induced reps and reps irreducible in the usual group-theoretical sense. However, this analogy is not complete. Indeed, the composite induced rep decomposition into simple ones is not always unique. This occurs whenever the site-symmetry group G_q is not the maximal isotropy one ($q \notin Q$). In this case, the group G_q is a subgroup of several maximal isotropy groups $G_{q'} (q' \in Q)$. Consequently, the induced rep decomposition (3.70) will be different for different points.

The theory of induced representations of space groups gives the answer to the question of whether it is possible to generate in the space of states of a given energy band the basis of localized functions. The answer to this question allows the symmetry connection between delocalized Bloch-type and localized Wannier-type crystalline orbitals to be obtained. This point is discussed in Sect. 3.3.

The following qualitative discussion should explain some features of band reps corresponding to real energy bands in crystals. Let a crystal be formed from isolated constituent atoms by decreasing the interatomic distances from very large ones to those corresponding to real crystalline structure. The crystal field may split the degenerate one-electron atomic levels due to symmetry requirements, leading to quite narrow energy bands, because of the interatomic interactions. The interatomic distances are sufficiently large that the crystalline orbitals corresponding to these bands are localized quite well at the atomic sites and are close to atomic functions. The Bloch states of these narrow energy bands span the spaces of some band reps that certainly have q -basis, *that is*, induced representations. These reps are induced by those irreps of site-symmetry groups of atoms that describe the transformation properties of atomic states generating the energy bands. The further decrease of the interatomic distances may considerably transform the energy bands (join them together into more complicated ones and later split them up again into other simple ones), but a new electronic state of arbitrary symmetry cannot arise nor can any state disappear. At the same time, the wavefunctions of all possible symmetry types may change, and corresponding one-electron energies may shift along the energy scale. Thus, an energy band corresponding to a band rep without a q -basis (*that is*, not an induced rep) may arise. However, this band, in joining with one or several neighboring ones, forms an energy band corresponding to a composite induced rep with q -basis. In the joint space of these band states, one can generate the basis of localized functions. Thus, the calculated one-electron energy band spectra of crystals may always be divided into bands connected with some simple or composite induced reps. When the interatomic distances are decreased to those in a real crystal, the atomic functions undergo more or less extensive modifications and become the

Wannier functions of a crystal (see Sect. 3.3). When the latter arise directly from atomic functions, one can use for them the same notation (s , p , d , and so on). Let the atoms be at Wyckoff positions with the site-symmetry group G_q . Localized functions transforming according to irreps of the group G_q correspond to the bands arising from atomic levels split by a crystalline field. If these Wyckoff positions belong to the set Q , the band states usually form the space of a simple induced rep. When atoms are at positions that do not belong to the set Q , the band states form the basis of a composite induced rep. If, when the interatomic distances are decreased, the energy bands cross one another, then the states of the resultant composite band also span the space of a composite induced rep. However, it may happen that this new band splits into several subbands related to localized functions that have centers of localization somewhat displaced from the atomic positions for further decreases in the interatomic distances. This case is typical for the electronic structure of crystals with covalent chemical bonding.

The information about the simple induced representations of the space groups can be given in the form of tables shown in the next section for the space groups O_h^5 , O_h^7 , and O_h^1 .

3.2.5 Simple Induced Representations for Cubic Space Groups O_h^1 , O_h^5 , and O_h^7

The correspondence between symbols of simple induced reps in q - and k -basis for $q \in Q$ and $k \in K$ is usually given in tables of simple induced reps having the following structure (e.g., Tables 3.8–3.10 for the space groups O_h^1 , O_h^5 , and O_h^7 , respectively).

The first two columns of the table contain the labels of the induced reps in the q -basis (these labels number the rows of the table); the international symbols (Roman letters a , b , c , and so on) of the Wyckoff positions (sites in direct space) and the Mulliken symbols of the irreps of the site-symmetry groups for these Wyckoff positions. For example, $d(a_{2u})$ and $d(e_u)$ are the labels of induced reps in q -basis for space group O_h^1 (Table 3.8). The remaining columns give the labels of induced reps in the k -basis, with the symbols of k -points (wavevectors) in the first row of the table and the indices of small irreps of little groups in subsequent rows. For example, 4^- in the column Γ means small irrep Γ_{4^-} . Below the table, supplementary information is given—the primitive translations, the coordinates and site-symmetry groups of Wyckoff positions in the direct lattice, and the analogous data for the reciprocal lattice. The correspondence between small representations of little groups for symmetry points in BZ is given in Table 3.11 (space group O_h^1) and in Table 3.12 (space group O_h^5).

In Tables 3.8–3.10 of simple induced reps, the labeling of the space-group irreps is that of [17], the labeling of the point-group irreps is that of [28], and the site points q are indexed as Wyckoff positions from [19].

Table 3.8 Simple induced representations of the $O_h^1-Pm\bar{3}m$ space group

q	β	Γ	R		M		X	
			a	b	a	b	a	b
a	a_{1g}	1^+	1^+	2^-	1^+	4^+	1^+	3^-
	a_{1u}	1^-	1^-	2^+	1^-	4^-	1^-	3^+
	a_{2g}	2^+	2^+	1^-	2^+	3^+	2^+	4^-
	a_{2u}	2^-	2^-	1^+	2^-	3^-	2^-	4^+
	e_g	3^+	3^+	3^-	1^+2^+	3^+4^+	1^+2^+	3^-4^-
	e_u	3^-	3^-	3^+	1^-2^-	3^-4^-	1^-2^-	3^+4^+
	t_{1g}	4^+	4^+	5^-	3^+5^+	2^+5^+	3^+5^+	1^-5^-
	t_{1u}	4^-	4^-	5^+	3^-5^-	2^-5^-	3^-5^-	1^+5^+
	t_{2g}	5^+	5^+	4^-	4^+5^+	1^+5^+	4^+5^+	2^-5^-
	t_{2u}	5^-	5^-	4^+	4^-5^-	1^-5^-	4^-5^-	2^+5^+
c			c	d	c	d	c	d
	a_{1g}	1^+3^+	5^+	4^-	4^+5^-	1^+5^-	$1^+3^-4^-$	$1^+2^+3^-$
	a_{1u}	1^-3^-	5^-	4^+	4^-5^+	1^-5^+	$1^-3^+4^+$	$1^-2^-3^+$
	b_{2g}	2^+3^+	4^+	5^-	3^+5^-	2^+5^-	$2^+3^-4^-$	$1^+2^+4^-$
	b_{2u}	2^-3^-	4^-	5^+	3^-5^+	2^-5^+	$2^-3^+4^+$	$1^-2^-4^+$
	a_{2g}	4^+	2^+3^+	1^-3^-	$2^+3^-4^-$	$1^-2^-3^+$	3^+5^-	1^-5^+
	a_{2u}	4^-	2^-3^-	1^+3^+	$2^-3^+4^+$	$1^+2^+3^-$	3^-5^+	1^+5^-
	b_{1g}	5^+	1^+3^+	2^-3^-	$1^+3^-4^-$	$1^-2^-4^+$	4^+5^-	2^-5^+
	b_{1u}	5^-	1^-3^-	2^+3^+	$1^-3^+4^+$	$1^+2^+4^-$	4^-5^+	2^+5^-
	e_g	4^+5^+	4^+5^+	4^-5^-	$1^-2^-5^+5^-$	$3^-4^-5^+5^-$	$1^-2^-5^+5^-$	$3^+4^+5^+5^-$
d	e_u	4^-5^-	4^-5^-	4^+5^+	$1^+2^+5^-5^+$	$3^+4^+5^-5^+$	$1^+2^+5^-5^+$	$3^-4^-5^-5^+$

In (aaa) units: $\mathbf{a}_1(100)$, $\mathbf{a}_2(010)$, $\mathbf{a}_3(001)$

Q : $O_h(m\bar{3}m)$ — $a(000)$, $b(1/2, 1/2, 1/2)$;

$D_{4h}(4/mmm)$ — $c(1/2, 1/2, 0)$, $d(1/2, 0, 0)$

In ($2\pi/a, 2\pi/a, 2\pi/a$) units: $\mathbf{b}_1(100)$, $\mathbf{b}_2(010)$, $\mathbf{b}_3(001)$

K : O_h — $\Gamma(000)$, $R(1/2, 1/2, 1/2)$; D_{4h} — $M(1/2, 1/2, 0)$, $X(1/2, 0, 0)$

According to the theory developed in previous sections, all the information about the induced reps of a given space group is contained in the table of its simple induced reps. Using these tables one can solve the following two purely mathematical problems:

1. Finding the irreducible components of the space-group reps induced by the irreps of all the possible site-symmetry subgroups for a given space group.
2. Finding the irreducible components of the site-symmetry group reps subduced by the irreps of the corresponding space group.

Table 3.9 Simple induced representations of the $O_h^5-Fm\bar{3}m$ space group

q	β	Γ	L		X	W	
			a	b		a	b
a	a_{1g}	1^+	1^+	2^-	1^+	1	2
	a_{1u}	1^-	1^-	2^+	1^-	1	2
	a_{2g}	2^+	2^+	1^-	2^+	2	1
	a_{2u}	2^-	2^-	1^+	2^-	2	1
	e_g	3^+	3^+	3^-	1^+2^+	1 2	1 2
b	e_u	3^-	3^-	3^+	1^-2^-	3 4	3 4
	t_{1g}	4^+	2^+3^+	1^-3^-	3^+5^+	3 5	4 5
	t_{1u}	4^-	2^-3^-	1^+3^+	3^-5^-	2 5	1 5
	t_{2g}	5^+	1^+3^+	2^-3^-	4^+5^+	4 5	3 5
	t_{2u}	5^-	1^-3^-	2^+3^+	4^-5^-	1 5	2 5
c	a_1	1^+2^-	1^+2^-		4^+3^-	5	
	a_2	2^+1^-	2^+1^-		3^+4^-	5	
	e	3^+3^-	3^+3^-		$3^+4^+3^-4^-$	5 5	
	t_1	4^+5^-	$2^+3^+1^-3^-$		$2^+5^+1^-5^-$	1 2 3 4 5	
	t_2	5^+4^-	$1^+3^+2^-3^-$		$1^+5^+2^-5^-$	1 2 3 4 5	
d	a_g	$1^+3^+5^+$	$1^+3^+2^-3^-$		$1^+4^+3^-4^-5^-$	1 2 5 5	
	a_u	$1^-3^-5^-$	$1^-3^-2^+3^+$		$1^-4^-3^+4^+5^+$	3 4 5 5	
	b_{1g}	$2^+3^+4^+$	$2^+3^+1^-3^-$		$2^+3^+3^-4^-5^-$	1 2 5 5	
	b_{1u}	$2^-3^-4^-$	$2^-3^-1^+3^+$		$2^-3^-3^+4^+5^+$	3 4 5 5	
	b_{2g}	4^+5^+	$1^+3^+1^-3^-$		$1^-2^-5^+5^-$	1 3 4 4 5	
	b_{2u}	4^-5^-	$1^-3^-1^+3^+$		$1^+2^+5^-5^+$	1 1 2 4 5	
	b_{3g}	4^+5^+	$2^+3^+2^-3^-$		$5^+1^-2^-5^-$	2 3 3 4 5	
	b_{3u}	4^-5^-	$2^-3^-2^+3^+$		$5^-1^+2^+5^+$	1 2 2 3 5	

In (aaa) units: $\mathbf{a}_1(0, 1/2, 1/2)$, $\mathbf{a}_2(1/2, 0, 1/2)$, $\mathbf{a}_3(1/2, 1/2, 0)$

Q : $O_h(m\bar{3}m)$ — $a(000)$, $b(1/2, 1/2, -1/2)$;

$T_d(\bar{4}3m)$ — $c(1/4, 1/4, 1/4)$; $D_{4h}(mmm)$ — $d(1/2, 0, 0)$.

In $(2\pi/a, 2\pi/a, 2\pi/a)$ units: $\mathbf{b}_1(-111)$, $\mathbf{b}_2(1-11)$, $\mathbf{b}_3(11-1)$

K : O_h — $\Gamma(000)$; D_{4h} — $X(0, 1/2, 1/2)$

D_{3d} — $L(1/2, 1/2, 1/2)$; D_{2d} — $W(1/4, 1/2, 3/4)$.

To solve these two problems, one also needs:

- The compatibility relation tables for the irreps of space groups [17].
- Tables of induced reps of crystallographic point groups [13].

We consider now in more detail the application of the tables of simple induced reps for the solution of the two problems mentioned above. Suppose one needs to find, for a given space group, the irreducible components of the space-group reps

Table 3.10 Simple induced representations of the O_h^7 — $Fd\bar{3}m$ space group

q	β	Γ	X	L	W	
					a	b
a	a_1	1^+2^-	1	1^+2^-	1	2
	a_2	1^-2^+	2	1^-2^+	2	1
	e	3^+3^-	1 2	3^+3^-	1 2	1 2
b	t_1	4^+5^-	2 3 4	$1^-2^+3^+3^-$	1 1 2	1 2 2
	t_2	4^-5^+	1 3 4	$1^+2^-3^+3^-$	1 2 2	1 1 2
				c	d	
c	a_{1g}	1^+5^+	1 3	$1^+2^-3^-$	$1^+2^-3^+$	1 2
	a_{1u}	1^-5^-	2 3	$1^-2^+3^+$	$1^-2^+3^-$	1 2
	a_{2g}	2^+4^+	2 4	$1^-2^+3^-$	$1^-2^+3^+$	1 2
d	a_{2u}	2^-4^-	1 4	$1^+2^-3^+$	$1^+2^-3^-$	1 2
	e_g	$3^+4^+4^+$	1 2 3 4	$1^-2^-3^+3^-3^-$	$1^-2^+3^+3^+3^-$	1 1 2 2
	e_u	$3^-4^-4^-$	1 2 3 4	$1^+2^+3^-3^+3^+$	$1^+2^-3^-3^-3^+$	1 1 2 2

For the direct and reciprocal lattice translation vectors and coordinates

of K -set points see Table 3.9.

Q : $T_d(\bar{4}3m)$ — $a(000)$, $b(1/2, 1/2, -1/2)$;

$D_{3d}(\bar{3}m)$ — $c(1/8, 1/8, 1/8)$, $d(-3/8, -3/8, 5/8)$.

Table 3.11 Space group O_h^1 : correspondence between small representations of little groups G_Γ , G_R , G_X , and G_M and irreducible representations of point groups O_h and D_{4h}

Γ, R	O_h	X, M	D_{4h}
1^+	a_{1g}	1^+	a_{1g}
1^-	a_{1u}	1^-	a_{1u}
2^+	a_{2g}	2^+	a_{2g}
2^-	a_{2u}	2^-	a_{2u}
3^+	e_g	3^+	b_{1g}
3^-	e_u	3^-	b_{1u}
4^+	t_{1g}	4^+	b_{2g}
4^-	t_{1u}	4^-	b_{2u}
5^+	t_{2g}	5^+	e_g
5^-	t_{2u}	5^-	e_u

induced by some irrep of the site-symmetry subgroup $G_q \subset G$. One has to consider four cases.

- (la) $q \in Q$ and $k \in K$. All the irreps in question can be found immediately from the table of simple induced reps. For example, all the irreps $(^*k, \beta)$ of the space group O_h^1 with $k \in K$ contained in the simple

Table 3.12 Space group O_h^5 : correspondence between small representations of little groups G_Γ , G_X , G_L , and G_W and irreducible representations of point groups O_h , D_{4h} , D_{3d} , and D_{2d}

Γ	O_h	X	D_{4h}	L	D_{3d}	W	D_{2d}
1^+	a_{1g}	1^+	a_{1g}	1^+	a_{1g}	1	a
1^-	a_{1u}	1^-	a_{1u}	1^-	a_{1u}	2	b
2^+	a_{2g}	2^+	a_{2g}	2^+	a_{2g}	3,4	e
2^-	a_{2u}	2^-	a_{2u}	2^-	a_{2u}		
3^+	e_g	3^+	b_{1g}	3^+	e_g		
3^-	e_u	3^-	b_{1u}	3^-	e_u		
4^+	t_{1g}	4^+	b_{2g}				
4^-	t_{1u}	4^-	b_{2u}				
5^+	t_{2g}	5^+	e_g				
5^-	t_{2u}	5^-	e_u				

Table 3.13 Compatibility relations for space group O_h^1 . For the Γ and X points, the compatibility relations for the space group O_h^1 coincide with those for the space group O_h^5 (see Table 3.12)

R	1^+	1^-	2^+	2^-	3^+	3^-	4^+	4^-	5^+	5^-
$\Lambda (\Gamma L)$	1	2	2	1	3	3	2, 3	1, 3	1, 3	2, 3
$S (R X)$	1	2	4	3	1, 4	2, 3	2, 3, 4	1, 3, 4	1, 2, 3	1, 2, 4
$T (R M)$	1	2	4	1, 3	2, 4	2, 5	1, 5	4, 5	3, 5	
M	1^+	1^-	2^+	2^-	3^+	3^-	4^+	4^-	5^+	5^-
$\Sigma (\Gamma M)$	1	2	4	3	4	3	1	2	2, 3	1, 4
$Z (X M)$	1	2	4	3	1	2	3	4	2, 4	1, 3
$T (R M)$	1	2	2	1	3	4	4	3	5	5

induced rep $d(a_{1g})$ are enumerated in the row $d(a_{1g})$ of Table 3.8: $\Gamma(1^+3^+) R(4^-) M(1^+5^-) X(1^+2^+3^-)$.

- (lb) $\mathbf{q} \in Q$ and $\mathbf{k} \notin K$. After using the table of simple induced reps, it is necessary to use the tables of compatibility relations. As an example the latter are given in Table 3.13 for the R and M points of the BZ. For example, the simple induced rep $d(a_{1g})$ of the group O_h^1 contains the irreps R_{4^-} and, according to Table 3.13 of compatibility relations, the irreps Λ_1, Λ_2 with $\mathbf{k} \notin K$ since $R_{4^-} \downarrow G_d = \Lambda_1 + \Lambda_2$.
- (1c) $\mathbf{q} \notin Q$ and $\mathbf{k} \in K$. First, the table of induced representations of point groups is used to obtain the decomposition (3.75), and then the table of simple induced reps may be used.
- (1d) $\mathbf{q} \notin Q$ and $\mathbf{k} \notin K$. All three tables (simple induced reps of a space group, induced representations of point groups, and compatibility relations) are necessary. All the four cases are considered in detail in [13] on the example of the space group D_{4h}^{14} (symmetry group of rutile structure). If we now seek the irreducible components of the site-symmetry group reps subduced

by a given space-group irrep $(*\mathbf{k}, \gamma)$ (problem 2), we also have four cases to consider.

- (2a) $\mathbf{k} \in K$ and $\mathbf{q} \in Q$. One finds the irrep $(*\mathbf{k}, \gamma)$ in question in the rows of the table of simple induced reps corresponding to the irreps of the site group. According to the Frobenius reciprocity theorem, the irrep β is contained in the reducible rep of the group $G_{\mathbf{q}}$ subduced by the irrep $(*\mathbf{k}, \gamma)$ of the space group G as many times as the symbol $(*\mathbf{k}, \gamma)$ is repeated in the corresponding row of the table of simple induced reps. For example, the rep of the site group $G_d = D_{4h}$ subduced by the irrep M_{5-} of the space group O_h^1 consists of the irreps a_{1g} and e_u (Table 3.13).
- (2b) $\mathbf{k} \in K$ and $\mathbf{q} \notin Q$. First, one finds the irreps α' contained in the decomposition of the rep of the group $G_{\bar{\mathbf{q}}}$ ($G_{\mathbf{q}} \subset G_{\bar{\mathbf{q}}}$ subduced by the irrep $(*\mathbf{k}, \gamma)$ (as is done in 2a). Then, using the table of induced representations of point groups, one decomposes the reps of the group $G_{\bar{\mathbf{q}}}$ subduced by the irreps α' of the group $G_{\bar{\mathbf{q}}}$.
- (2c) $\mathbf{k} \notin K$ and $\mathbf{q} \in Q$. Using the compatibility-relations perovskite table, one completes the simple induced reps table by one additional column only in the rows corresponding to the irreps of the group $G_{\bar{\mathbf{q}}}$. Then one proceeds as in case 2a.
- (2d) $\mathbf{k} \notin K$ and $\mathbf{q} \notin Q$. The irreducible components of the subduced rep can be found in two steps: first, the compatibility-relations table is used as in case 2c, and then the table of induced representations of point groups, as in case 2b.

Unfortunately simple induced reps for 230 space groups cannot be found on any Internet site. One can find them in the book by Kovalev [29], but the irreps notations in this book sometimes differ from those used by Miller and Love [17] and on the site [16]. The latter notations are introduced in tables of simple induced reps of 25 frequently used space groups given in [13]. In this section we reproduce from [13] the simple induced tables for three cubic space groups belonging to the crystal class O_h : O_h^1 (simple cubic lattice; see the Brillouin zone in Fig. 3.1) and O_h^5 , O_h^7 (face-centered cubic lattices, the Brillouin zone in Fig. 3.2). The symmetry of the perovskite form of SrZrO_3 , MgO , and silicon crystals is described by the groups O_h^1 , O_h^5 , and O_h^7 , respectively. These crystals are examples of systems with different types of chemical bonding: the mixed ionic-covalent bonding (in SrZrO_3 the Sr atom is in the Sr^{2+} state, the Zr–O bonding is essentially covalent), ionic bonding (MgO), and covalent bonding (Si). In the next subsection we illustrate the use of the simple induced representations in the electronic-structure theory for these relatively simple structures.

3.2.6 Symmetry of Atomic and Crystalline Orbitals in MgO , Si, and SrZrO_3 Crystals

The space symmetry of crystalline orbitals generated by atomic orbitals of the LCAO basis can be found from the tables of induced representations of space groups considered in previous section. The knowledge of space symmetry of

crystalline orbitals allows the pictures of electronic bands given as a result of electronic-structure calculations to be understood. It is also useful in localized crystalline orbitals generation (see Sect. 3.3). As an example, we show the energy bands for MgO (Fig. 3.4), silicon (Si) (Fig. 3.5), and SrZrO₃ crystals (Fig. 3.3). The LCAO calculations of these crystals were made using the Hartree–Fock LCAO method (see Chap. 4). *MgO* crystal has rocksalt structure with symmorphic space group O_h^5 , Si crystal has diamond structure with nonsymmorphic space group O_h^7 , and SrZrO₃ crystal has perovskite structure with symmorphic space group O_h^1 ; see Sect. 2.3.2. The translation symmetry of the first two crystals is described by the same face-centered cubic lattice of the third one—by the simple cubic lattice. The point group $F = O_h$ of all the three crystals is holosymmetric (coincides with point group F^0 of the cubic lattice). For the first two crystals, the wavevector belongs to the same Brillouin zone (Fig. 3.2), the representation domain coincides with the basic domain, and the symmetry points of BZ are the same: $\Gamma(0, 0, 0)$, $X(1/2, 1/2, 0)$, $L(1/2, 1/2, 1/2)$, and $W(1/4, 1/2, 3/4)$ with the wavevector point groups O_h , D_{4h} , D_{3d} , and D_{2d} , respectively. For the third crystal, the wavevector belongs to the simple cubic lattice Brillouin zone (Fig. 3.1), the representation domain also coincides with basic domain, and the symmetry points of BZ are $\Gamma(0, 0, 0)$, $R(1/2, 1/2, 1/2)$, $X(1/2, 0, 0)$, and $M(1/2, 1/2, 0)$ with the wavevector point groups O_h , O_h , D_{4h} , and D_{4h} , respectively. For the symmorphic space groups O_h^5 and O_h^1 , the small representations of little groups of symmetry points of BZ coincide with the ordinary (vector) irreducible representations of the corresponding wavevector point groups. For nonsymmorphic space group O_h^7 , the small representations of little groups G_Γ , G_X , G_L , and G_W were considered in Sect. 3.1.4. For the Γ and L points, the notations given in Table 3.12 are used as the corresponding small representations are p -equivalent to ordinary representations of point groups O_h and D_{3d} . For the X and W points, the small representations are not p -equivalent to ordinary irreducible representations of point groups D_{4h} and D_{2d} , respectively. The notations for these representations were given in Sect. 3.2.4.

Let us connect the pictures of the calculated band structures with the symmetry of crystalline orbitals. As for MgO and silicon crystals, the dimensions of the corresponding small representations are different at the X and W points, and the splitting of the valence band to one-sheet and three-sheet subbands takes place for MgO, but for *Si* crystal the valence band is not split. In the symmetry directions of the Brillouin zone, the compatibility relations are used to explain the energy-level splittings. The compatibility relations for space groups O_h^5 and O_h^7 are given in Table 3.14 and in Table 3.13 for space group O_h^1 .

For the symmetry directions in the Brillouin zone $\Delta(\Gamma X)$, $\Lambda(\Gamma L)$, Σ (see Fig. 3.2), the small representations of both space groups are p -equivalent to ordinary irreducible representations of point groups C_{4v} , C_{3v} , and C_{2v} . The notations of these representations are taken from [17]. For symmetry directions on the surface of the Brillouin zone $Z(XW)$, S , small representations of space group O_h^5 are p -equivalent to ordinary irreducible representations of point group C_{2v} for the symmetry direction Q —to ordinary irreducible representations of group C_s . For the

Table 3.14 Compatibility relations for space groups O_h^5 and O_h^7

$\Gamma(O_h^5, O_h^7)$	1^+	1^-	2^+	2^-	3^+	3^-	4^+	4^-	5^+	5^-
$\Delta(\Gamma X)$	1	2	3	4	1,3	2,4	2,5	4,5	1,5	3,5
$\Delta(\Gamma L)$	1	2	2	1	3	3	2,3	1,3	1,3	2,3
Σ	1	2	4	3	1,4	2,3	2,3,4	1,3,4	1,2,3	1,2,4
$X(O_h^5)$	1^+	1^-	2^+	2^-	3^+	3^-	4^+	4^-	5^+	5^-
Δ	1	2	2	1	3	4	4	3	5	5
$Z(XW)$	1	2	3	4	1	2	4	3	2,3	1,4
S	1	2	4	3	4	3	1	2	2,3	1,4
$X(O_h^7)$	1	2	3	4						
Δ	1,4	2,3	5	5						
$Z(XW)$	1	1	1	1						
S	1,3	2,4	3,4	1,2						
$L(O_h^5, O_h^7)$	1^+	1^-	2^+	2^-	3^+	3^-				
A	1	2	2	1	3	3				
Q	1	1	2	2	1,2	1,2				
$W(O_h^5)$	1	2	3	4	5	$W(O_h^7)$	1	2		
Z	1	2	2	1	3,4		1	1		
Q	1	2	1	2	1,2		1,2	1,2		

Table 3.15 Band representations of space groups O_h^5 and O_h^7 for upper valence bands of MgO and Si crystals

	Γ	X	L	W
MgO – O_h^5				
$b(1/2, 1/2, 1/2)$	a_{1g}	1^+	1^+	2^- 4
	t_{1u}	5^-	$2^- 5^-$	$1^+ 3^+$ 1 5
Si – O_h^7				
$a(0\ 0\ 0)$	a_1	$1^+ 2^-$	1	$1^+ 2^-$ 1
	t_2	$4^- 5^+$	1 3 4	$1^+ 2^- 3^+ 3^-$ 1 2 2

nonsymmorphic space group O_h^7 , small representations in the symmetry direction Z are not p -equivalent to ordinary irreducible representations of point group C_{2v} (see Sect. 3.2.2).

In Tables 3.15 and 3.16, we give the notations of induced representations in k -basis for symmetry points of the Brillouin zone. We include only the band representations for upper valence bands of all the crystals under consideration.

These bands are induced by the oxygen atom $2s, 2p$ states in MgO; by the silicon atom $3s, 3p$ states in silicon; and by the strontium atom $4p$ -states and oxygen atom $2s, 2p$ states in SrZrO_3 . The symmetry of the corresponding crystalline orbitals

Table 3.16 Band representations of upper valence bands in SrZrO₃ crystal induced from Sr 4*p*-, O 2*s*-, and O 2*p*-atom-like states

Atom states	q-basis	Γ	R	M	X
Sr 4 <i>p</i> –	(<i>b</i> , <i>t</i> _{1<i>u</i>})	4 [–]	5 ⁺	2 [–] 5 [–]	1 ⁺ 5 ⁺
O 2 <i>s</i> –	(<i>d</i> , <i>a</i> _{1<i>g</i>})	1 ⁺ 3 ⁺	4 [–]	1 ⁺ 5 [–]	1 ⁺ 2 ⁺ 3 [–]
O 2 <i>p</i> _z –	(<i>d</i> , <i>a</i> _{2<i>u</i>})	4 [–]	1 ⁺ 3 ⁺	1 ⁺ 2 ⁺ 3 [–]	1 ⁺ 5 [–]
O 2 <i>p</i> _{x,y} –	(<i>d</i> , <i>e</i> _u)	4 [–] 5 [–]	4 ⁺ 5 ⁺	3 ⁺ 4 ⁺ 5 [±]	3 [–] 4 [–] 5 [±]

is given in Figs. 3.3–3.5 and was extracted directly from the tables of the simple induced representations of the corresponding space groups given in Sect. 3.2.5 as the Wyckoff positions occupied by atoms belong to the Q sets in all three structures under consideration. For all three crystals the short symbol of the BR in **k**-basis contains only the indices of the small IRs for the most symmetrical points of the BZ because the indices for all other IRs contained in the BR are determined with the help of compatibility relations. These are the states responsible for four-sheet valence bands in the first two crystals (Figs. 3.4 and 3.5) and for the 6- and 9-sheet valence bands in SrZrO₃ crystal (Fig. 3.3). Due to the considered symmetry difference of crystalline orbitals in MgO and Si crystals, the nature of chemical bonding in these crystals is also different. Indeed, in ionic MgO crystal, the splitting of the valence band allows the crystalline orbitals localized on an oxygen atom to be generated and transformed over *a*_{1*g*} and *t*_{1*u*} irreducible representations of the oxygen site-symmetry group *O_h*. In covalent Si crystal, all four sheets of the valence band have to be included in localization so that the localized orbitals found are centered at the middle of the Si–Si bond.

In SrZrO₃ crystal, oxygen 2*s* functions transform according to $\beta = a_{1g}$ IR of the oxygen site-symmetry group $G_q = D_{4h}$ and generate a 3-sheeted BR. The symmetry of states in this band is fully determined by the 2*s*-function of one of three oxygens in the primitive cell and may be labeled by the symbol (*d*, *a*_{1*g*}) as oxygen atoms occupy Wyckoff position *d* in space group *O_h*¹. In Table 3.16 this band, with the symbol of the BR (*d*, *a*_{1*g*}), is given in **k**-basis (Γ , *R*, *M*, *X* are the symmetry points of the BZ). In Sect. 3.2.4 we defined simple and composite BRs. A BR is simple if it does not consist of two or more BRs of a smaller dimension. All simple BRs for a given space group are generated by the IRs of site-symmetry groups of just a few points in the Wigner–Seitz cell of the direct lattice.

In our examples, all the induced irreps are simple, excluding the BR corresponding to the 6-sheeted lower valence subband (see Fig. 3.3). This band representation is a composite one as it is formed by two simple band representations (*d*, *a*_{1*g*}) and (*b*, *t*_{1*u*}) induced by O 2*s*- and Sr 4*p*-states, respectively. Analysis of the space symmetry of crystalline orbitals is used to consider the possible centers of localization of chemical bonding in crystals. This task requires the Wannier-function definition and is considered in the next section.

3.3 Symmetry of Localized Crystalline Orbitals. Wannier Functions

3.3.1 *Symmetry of Localized Orbitals and Band Representations of Space Groups*

The localized molecular orbitals (LMO) are extensively used not only for the chemical-bonding analysis in molecules but also in the local correlation methods [39] (we consider the problem of electron correlation in molecules and crystals in Chap. 5). The LMO are generated from the canonical MO occupied by electrons and found in the Hartree–Fock or DFT calculations. This generation is based on one or other localization criteria [40].

Localized crystalline orbitals (LCO) are generated from a canonical delocalized Bloch functions (CO). As in the case of the molecules, one or other localization criteria are used. The orthonormalized LCO in crystals are known as Wannier functions. Wannier functions (WFs) have attracted much attention in solid-state physics since their first introduction in 1937 [41] and up to now. The analytical behavior of Bloch functions of energy bands in $\mathbf{k}$ -space determines the degree of localization of the corresponding Wannier functions in $\mathbf{r}$ -space [42, 43]. A useful concept of band (induced) representations has been introduced in the theory of crystals, according to which the position of symmetry localization and the symmetry properties of Wannier functions for a given energy band define unambiguously the symmetry properties of the corresponding Bloch functions [13]. But the last decade has been marked by an outburst of interest in WFs, owing to the development of new theories related to them, and effective methods for their generation [5, 44–46].

Due to their high localization, WFs are especially beneficial when applied in the following areas of solid-state theory:

1. Linear scaling (so-called $O(N)$) algorithms for calculation of crystalline electronic structure are based on the concept of WFs [48].
2. WFs play an important role in the theory of electronic polarization in insulators [49]. The electronic polarization itself and related properties can be expressed simply via the centroids of WFs, connected with the valence-band states.
3. Wannier functions are often used as a convenient basis for describing the local phenomena in solids, such as point defects, excitons, surfaces [50].
4. They can serve as a useful tool in the solution of the problem of electron correlation in crystals [39].
5. WFs, being spatially localized combinations of Bloch functions, thus form a natural basis for analysis of chemical bonding in crystals [45, 51, 52].

The background of LOs symmetry analysis is the theory of BRs of space groups G . This analysis is equally applicable to localized Wannier orbitals, (LWOs) *that is*, to an orthonormal set of LOs. We describe the main principles of this theory related to the examined problem.

The LOs $V_{i1p}^{(\beta)}(\mathbf{r}) \equiv V_i^{(\beta)}(\mathbf{r} - \mathbf{q}_1^{(p)})$ are the basis functions of the irreducible representation (IR) β of the site-symmetry group $G_{\mathbf{q}^{(p)}} \subset G$ corresponding to their centering point (centroid) $\mathbf{q}_1^{(p)}$ (index p distinguishes the symmetry nonequivalent points in the space of the crystal):

$$(R|\hat{\mathbf{v}}_R)V_{i1p}^{(\beta)}(\mathbf{r}) = \sum_{i'} d_{i'i}^{(\beta)}(R)V_{i'1p}^{(\beta)}(\mathbf{r}) \quad (3.71)$$

where $(R|\hat{\mathbf{v}}_R) \in G_{\mathbf{q}^{(p)}}$, $d^{(\beta)}(R)$ is the matrix mapping the element $(R|\hat{\mathbf{v}}_R)$ in the IR β . For example, in crystal SrZrO_3 , index $p = 1, 2, 3$ numbers symmetry nonequivalent Sr, Zr, and one of the three oxygen atoms. Applying symmetry operations from the decomposition of the group G into the left cosets with respect to the site group $G_{\mathbf{q}^{(p)}}$

$$G = \sum_j (R_j|\mathbf{v}_j + \mathbf{a}_n) \cdot G_{\mathbf{q}^{(p)}} \quad (3.72)$$

to the functions $V_{i1p}^{(\beta)}(\mathbf{r})$

$$V_{ijp}^{(\beta)}(\mathbf{r} - \mathbf{a}_n) \equiv (R_j|\mathbf{v}_j + \mathbf{a}_n)V_{i1p}^{(\beta)}(\mathbf{r}) \quad (3.73)$$

one can obtain the complete basis in the space $\Omega_p^{(\beta)}$ of the reducible representation of the group G induced from the IR β of the group $L_{\mathbf{q}^{(p)}}$. The functions $V_{ijp}^{(\beta)}(\mathbf{r} - \mathbf{a}_n) \equiv V_i^{(\beta)}(\mathbf{r} - \mathbf{q}_{j,n}^{(p)} - \mathbf{a}_n)$ are centered at the points $\mathbf{q}_{j,n}^{(p)} \equiv (R_j|\mathbf{v}_j + \mathbf{a}_n)\mathbf{q}_1^{(p)} = R_j\mathbf{q}_1^{(p)} + \mathbf{v}_j + \mathbf{a}_n$. Such a basis consisting of the LOs $V_{ijp}^{(\beta)}(\mathbf{r} - \mathbf{a}_n) \equiv V_\tau(\mathbf{r} - \mathbf{a}_n) \equiv V_t(\mathbf{r})$ is called the $\mathbf{q}$ -basis (Sect. 3.2.2). The index τ replaces i, j, β, p , and the index t replaces $\tau, \mathbf{n}$ to simplify a traditional group-theoretical notation. This basis is fully determined by its single representative (e.g., $V_{11p}^{(\beta)}(\mathbf{r})$). All the other basis functions of the same BR can be obtained from it by the symmetry operations (3.73). A BR is characterized in $\mathbf{q}$ -basis by the site $\mathbf{q}^{(p)}$ (the centroid of $V_{i1p}^{(\beta)}(\mathbf{r})$) and the IR β of the site group $G_{\mathbf{q}^{(p)}} : (\mathbf{q}^{(p)}, \beta)$ is a symbol of the BR in $\mathbf{q}$ -basis. For example, in MgO crystal, oxygen $2s$ -functions transform according to $\beta = a_{1g}$ IR of the site-symmetry group $G_{\mathbf{q}^{(1)}} = O_h$, and decomposition (3.72) consists of 1 term as the point group of the crystal is O_h . The functions $V_{i1p}^{(a_{1g})}(\mathbf{r} - \mathbf{a}_n)$ are centered at the oxygens in a whole direct lattice. Silicon crystal has space group O_h^7 , diamond-type lattice with two atoms per unit cell, occupying the Wyckoff position a with the site-symmetry group $G_a = T_d$. The calculated upper valence and lower conduction bands, shown in Fig. 3.5, are composite (for each wavevector value there are $4 + 4 = 8$ Bloch states). The corresponding induced representation is engendered by a_1, t_2 irreps of the point group G_a , corresponding by symmetry to the s, p states of Si atom. The upper valence band in silicon crystal is connected with the one-electron states localized not on the Si atom but on the Si-Si bond middle (Wyckoff position c with the site-symmetry group D_{3d}). This can be found by inducing the four-sheet upper valence-band states from the

identity representation a_{1g} of the point group D_{3d} . The lower conduction-band states symmetry is defined by the induction from the irrep a_{2u} of the same point group. Therefore, these two band representations may be labeled by the symbols $(c, a_{1g}), (c, a_{2u})$.

As the third example of the band representations generated, we consider SrZrO_3 crystal. The configurations of valence electrons in free atoms are

$$\text{O} - 2s^2 2p^4, \quad \text{Sr} - 4p^6 5s^2, \quad \text{Zr} - 4d^2 5s^2 \quad (3.74)$$

The semicore $4p$ -states of Sr atom are included in (3.74) as they take part in the valence-band structure. The cubic phase of SrZrO_3 with the space group

$$Pm\bar{3}m$$

(O_h^1 , a simple cubic lattice) consists of one formula unit (5 atoms) in the primitive unit cell. Atoms Sr, Zr, and O occupy Wyckoff positions (Cartesian coordinates are given in units of lattice constant of the crystal) b (1/2, 1/2, 1/2), a (0, 0, 0) (site group O_h for both), and d (0, 0, 1/2) (site group D_{4h}), respectively. Figure 3.3 shows the valence energy bands of this crystal calculated by HF LCAO method with the help of CRYSTAL03 code [21]. Thirty electrons per primitive unit cell of SrZrO_3 crystal occupy 15 one-electron levels for each $\mathbf{k}$ -point in the BZ. The 15-sheeted valence band consists of two subbands (6 and 9 sheets). The analysis of the projected densities of states shows that the lower 6-sheeted subband is formed by Sr $4p$ - and O $2s$ -states and the upper 9-sheeted band is connected mainly with O $2p$ -states. These free-atom electron states are transformed by the interatomic interaction in crystalline LOs. The latter basis (just as the basis of canonical Bloch one-electron states) may be used to describe the electronic structure of the crystal and calculate its properties. In the SrZrO_3 crystal, two induced BRs correspond to six- and nine-sheeted bands. As is seen from Table 3.16, the states of six-sheeted band are induced by LO of the symmetry a_{1g} of oxygen site-symmetry group D_{4h} (Wyckoff position d) and by LOs of the symmetry t_{1u} of Sr-atom site-symmetry group O_h (Wyckoff position b), that is, by O $2s$ - and Sr $4p$ -atomic-like states. The states of the nine-sheeted band are induced by LOs of the symmetry a_{2u} and e_u of oxygen site-symmetry group D_{4h} , that is, by O $2p$ -atomic-like states. In SrZrO_3 crystal, oxygen $2s$ -functions transform according to $\beta = a_{1g}$ IR of the site-symmetry group $G_q = D_{4h}$, and decomposition consists of 3 terms as the point group of the crystal is O_h . The functions $V_{ijp}^{(a_{1g})}(\mathbf{r} - \mathbf{a}_n)$ are centered on the oxygens in a whole direct lattice ($j = 1, 2, 3$ numbers oxygens in one primitive cell). This is an example of the $\mathbf{q}$ -basis corresponding to a 3-sheeted BR, induced by O $2s$ -type atomic states. This basis is fully determined by a $2s$ -function of one of the three oxygens in the primitive cell and may be labeled by the symbol (d, a_{1g}) as oxygen atoms occupy Wyckoff position d in space group O_h^1 .

Resolving this BR into IRs of the space group G , one gets the indices of the BR in $\mathbf{k}$ -basis (Bloch basis). The short symbol of the BR in $\mathbf{k}$ -basis contains only the indices of the small IRs for the most symmetrical points of the BZ because

the indices for all other IRs contained in the BR are determined with the help of compatibility relations. For example, in Table 3.16 the BR (d, a_{1g}) is given in $\mathbf{k}$ -basis (Γ, R, M, X are the symmetry points of the BZ).

In our example, the BR corresponding to the 6-sheeted valence band is a composite one as it is formed by two simple band representations (d, a_{1g}) and (b, t_{1u}) induced by O $2s$ - and Sr $4p$ -states, respectively.

From the theory of the band representations of space groups, it follows that the generation of LOs corresponding to a given simple or composite energy band is possible only if the canonical (Bloch) orbitals of this band form the basis of some simple or composite BR. This analysis permits not only to establish the principal possibility to construct LOs but also to define the possible positions of their centroids $\mathbf{q}^{(p)}$ and their symmetry with respect to the site-symmetry group $G_{\mathbf{q}^{(p)}}$. The latter is not always unambiguous due to the fact that there are the BRs that have different symbols in $\mathbf{q}$ -basis, but the same index in $\mathbf{k}$ -basis, or there are the composite BRs that can be decomposed into simple ones by several ways (see Sect. 3.2.4).

Thus, the symmetry analysis consists of a procedure of identifying the localized orbitals symmetry from the symmetry of the canonical orbitals of the energy band under consideration, or of establishing the fact that the construction of LOs from the canonical orbitals chosen is impossible for the reasons of symmetry.

When calculating the electronic structure of a crystal, its cyclic model is used, *that is*, the model of a finite crystal with periodic boundary conditions—a supercell, consisting of N unit cells. Generally, when a numerical integration over the BZ is carried out as a summation over a set of special points of the BZ, it means that a cyclic model of a certain size is introduced for the crystal. The relation between the symmetry group G of the model of an infinite crystal and the symmetry group $G^{(N)}$ of a corresponding cyclic model and their IRs and BRs has been studied in detail in [53]. The localized orbitals of the model of an infinite crystal are well approximated by the localized orbitals of a cyclic model with a size slightly exceeding the region of their localization.

We assume that the canonical delocalized orbitals $\varphi_{m\mu}^{(\gamma)}(\mathbf{k}, \mathbf{r}) \equiv \varphi_{\sigma}(\mathbf{k}, \mathbf{r}) \equiv \varphi_s(\mathbf{r})$ (the index m numbers the basis vectors of IR γ with wavevector $\mathbf{k}$, and μ discriminates between the independent bases of equivalent IRs; the index σ replaces γ, m, μ , and s replaces $\sigma, \mathbf{k}$) of an energy band under consideration form a basis in the space Ω of some simple BR of the group $G^{(N)}$ of a crystal (index p is omitted for simplicity). The same space Ω is spanned also by the set of LOs $V_{ij}^{(\beta)}(\mathbf{r} - \mathbf{a}_n) \equiv V_i(\mathbf{r})$. The delocalized and localized bases are bounded by a linear transformation in the space Ω :

$$V_i(\mathbf{r} - \mathbf{a}_n) = \sum_{\mathbf{k}} \exp(-i\mathbf{k}\mathbf{a}_n) \sum_{\sigma} U_{\sigma, \tau}(\mathbf{k}) \varphi_{\sigma}(\mathbf{k}, \mathbf{r}), \quad \text{or} \quad (3.75)$$

$$V_i(\mathbf{r}) = \sum_s U_{st} \cdot \varphi_s(\mathbf{r}) \quad \text{with} \quad U_{st} = U_{\sigma, \tau}(\mathbf{k}) \cdot \exp(-i\mathbf{k}\mathbf{a}_n) \quad (3.76)$$

If the matrix U is unitary and the functions $\varphi_s(\mathbf{r})$ are orthonormalized, the functions $V_l(\mathbf{r})$ form an orthonormal system of LWOs $V_l(\mathbf{r}) = W_l(\mathbf{r})$.

Their localization extent depends on the choice of the matrix $U_{\sigma,\tau}(\mathbf{k})$ in (3.76). The existence of Wannier functions decreasing exponentially at infinity (for the model of an infinite crystal) is established in many cases. The different localization criteria used for the generation of localized orbitals in crystals are considered in the next subsection.

3.3.2 Localization Criteria in Wannier-Function Generation

The *general method* of the most localized Wannier-function (WF) generation exists only for the one-dimensional case and was offered by Kohn [55].

It is a variational method based on the first-principles approach, *that is*, without preliminary knowledge of Bloch-type delocalized functions. The localized functions with the symmetry of Wannier functions and depending on some number of parameters are used.

If spin variables are ignored, the one-determinant wavefunction for the system of M electrons occupying M Bloch-type states can be written as

$$\Psi_0 = (M!)^{-1/2} \det \left| (\Phi^{(\varphi)})_{\tau k, i} \right| = (M!)^{-1/2} \det \left| (\Phi^W)_{sn, i} \right| \quad (3.77)$$

where $\Phi^{(\varphi)}$ and Φ^W are Bloch and Wannier functions, respectively,

$$(\Phi^{(\varphi)})_{\tau k, i} = \varphi_{\tau k, i}(\mathbf{r}_i) \quad (3.78)$$

$$(\Phi^W)_{sn, i} = W_s(\mathbf{r}_i - \mathbf{a}_n) \quad (3.79)$$

and $\mathbf{r}_i$ —coordinate of the i th electron ($i = 1, 2, \dots, M$).

The total energy E_0 per cell is

$$E_0 = M^{-1} \left(\Psi_0, \sum_{i=1}^M H_i \Psi_0 \right) = M^{-1} \sum_{\tau, k} E_{\tau, k} = \sum_s (W_s(\mathbf{r}), H W_s(\mathbf{r})) \quad (3.80)$$

The better the initial modeling localized functions approximate WF $W_s(\mathbf{r})$, the closer to the minimal value E_0 is the value of the total energy calculated on these modeling functions. Thus, the variational principle assuming a variation of parameters of modeling functions is used to minimize the value of the total energy calculated on such functions.

Before calculation of the total energy on the basis of the trial localized functions $f_s(\mathbf{r}, \alpha, \beta, \dots)$ (where $\alpha, \beta, \dots$ are variational parameters), their orthonormalization is made. Functions $f_s(\mathbf{r} - \mathbf{a}_n)$ are orthogonalized by means of a procedure suggested by Des Cloizeaux [54]. This procedure consists of construction of the orthonormalized trial Bloch functions $\psi_s(\mathbf{r}, \mathbf{k})$:

$$\psi_s(\mathbf{r}, \mathbf{k}) = M^{-1/2} \sum_n \exp(i\mathbf{k}\mathbf{a}_n) \left\{ \sum_{s'} f_{s'}(\mathbf{r} - \mathbf{a}_n) \left[S^{(\psi)^{-1/2}}(\mathbf{k}) \right]_{s's} \right\} \quad (3.81)$$

where $S^{(\psi)}(\mathbf{k})$ is an overlap matrix of trial Bloch functions, directly constructed of trial localized functions $f_s(\mathbf{r} - \mathbf{a}_n)$:

$$\left[S^{(\psi)}(\mathbf{k}) \right]_{s's} = \sum_n (f_{s'}(\mathbf{r}), f_s(\mathbf{r} - \mathbf{a}_n)) \exp(i\mathbf{k}\mathbf{a}_n) \quad (3.82)$$

Then the modeling localized functions $W_s^{(m)}(\mathbf{r}) = W_s^{(m)}(\mathbf{r}, \alpha, \beta, \dots)$ are defined. These functions depend on the same parameters as function $f_s(\mathbf{r}, \alpha, \beta, \dots)$ does

$$W_s^{(m)}(\mathbf{r}) = M^{-1/2} \sum_k \psi_s(\mathbf{r}, \mathbf{k}) \quad (3.83)$$

and are substituted in (3.83) with the purpose of minimization of the total energy E_0 .

The advantages of the method are the following: WF generation does not require preliminary Bloch-function calculation, and the WF symmetry is taken into account at a stage of choice of trial modeling functions. Disadvantages of the method: the procedure is labor consuming in realization; the WF obtained are approximate, and their differences from the exact WF depend on the choice of the trial modeling functions; there is no universal procedure of a choice of basis of trial functions for different crystals; and use of the one-determinant approximation for vacant states WF is not quite correct.

The method of WF generation using the *Slater–Koster interpolation procedure* was suggested in [56]. In this method a group of one-electron energy bands is chosen and described by model Hamiltonian matrices $H(\mathbf{k})$:

$$\sum_{\mu} H_{\nu\mu}(\mathbf{k}) e_{\mu\tau}(\mathbf{k}) = E_{\tau\mathbf{k}} e_{\nu\tau}(\mathbf{k}) \quad (3.84)$$

where $e(\mathbf{k})$ and $E_{\tau\mathbf{k}}$ are eigenvectors and eigenvalues of a matrix model Hamiltonian $H(\mathbf{k})$ that should coincide with the eigenvalues of the exact Hamiltonian matrix in the given point $\mathbf{k}$. For the model Hamiltonian, Fourier decomposition is used:

$$H(\mathbf{k}) = \sum_n \varepsilon(\mathbf{a}_n) \exp(-i\mathbf{k}\mathbf{a}_n) \quad (3.85)$$

The WF is defined as

$$W_s(\mathbf{r}\mathbf{a}_n) = \frac{V_a}{(2\pi)^3} \int d\mathbf{k} \exp(-i\mathbf{k}\mathbf{a}_n) \sum_{\tau} e_{\tau s}(\mathbf{k}) \varphi_{\tau}(\mathbf{r}, \mathbf{k}) \quad (3.86)$$

so that Fourier coefficients $\varepsilon_{s's}(\mathbf{a}_n)$ (Slater–Koster parameters) are elements of a Hamiltonian matrix in the basis of WF:

$$\varepsilon_{s's}(\mathbf{a}_n) = \int W_{s'}^*(\mathbf{r} - \mathbf{a}_n) H W_s(\mathbf{r}) d\mathbf{r} \quad (3.87)$$

For well-localized WF, values $\varepsilon_{s's}(\mathbf{a}_n)$ quickly decrease with increase of $|\mathbf{a}_n|$. Therefore, in this case in decomposition (3.90), it is enough to consider a small amount of the matrices $\varepsilon(\mathbf{a}_n)$ corresponding to small values of translation vectors. Additional reduction of the number of independent Slater–Koster parameters is possible when the symmetry is taken into account. The remaining independent elements of matrices $\varepsilon(\mathbf{a}_n)$ can be found by means of a least-squares method, adjusting eigenvalues of a matrix $H(\mathbf{k})$ to the calculated band structure. Matrices of eigenvectors $e(\mathbf{k})$ for well-adjusted modeling Hamiltonian are matrices of the unitary transformation $U(\mathbf{k})$ connecting Bloch functions with localized WF.

There is still an uncertainty in the choice of relative phase multipliers for matrices $U(\mathbf{k})$ (or) $e(\mathbf{k})$ at different $\mathbf{k}$ (this problem can be solved only in crystals with inversion symmetry [57]). Let $u_s(\mathbf{r}, \mathbf{k})$ be periodic parts of Bloch functions $\psi_s(\mathbf{r}, \mathbf{k})$:

$$u_s(\mathbf{r}, \mathbf{k}) = \exp(-i\mathbf{k} \cdot \mathbf{r}) \psi_s(\mathbf{r}, \mathbf{k}) \quad (3.88)$$

Phase multipliers at matrices $U(\mathbf{k})$ need to be chosen so that decomposition coefficients $V_j(s, \mathbf{k})$ of functions $u_s(\mathbf{r}, \mathbf{k})$ on plane waves

$$u_s(\mathbf{r}, \mathbf{k}) = \sum_j V_j(s, \mathbf{k}) \exp(i\mathbf{K}_j \cdot \mathbf{r}) \quad (3.89)$$

remained real (this is possible if the space group of symmetry of a crystal contains an inversion).

Advantages of the method: for WF generation it is possible to choose any groups of energy band—occupied, vacant, or both; the use of expected WF symmetry reduces the number of independent Slater–Koster parameters.

Disadvantages of the method: an efficient procedure for the case when the lattice has no the center of inversion it is not developed; the WF maximal localization criteria is not formulated; the method is complex enough in realization. The recently developed WF generation method of Marzari and Vanderbilt [44, 58] extends to crystalline solids the Boys[36] criteria of localized MO generation (see Sect. 3.3.1). The localized WF (let their number be N for the primitive unit cell) are found by the minimization of the functional

$$I = \sum_{s=1}^N \left[\langle \mathbf{r}^2 \rangle_s - \langle \mathbf{r} \rangle_s^2 \right] \quad (3.90)$$

where

$$\langle \mathbf{r}^2 \rangle_s = \int \mathbf{r}^2 |W_s(\mathbf{r})|^2 d\mathbf{r} \quad (3.91)$$

$$\langle \mathbf{r} \rangle_s = \int \mathbf{r} |W_s(\mathbf{r})|^2 d\mathbf{r} \quad (3.92)$$

Minimization of (3.90) is made in reciprocal space, for which expressions (3.91) and (3.92) can be rewritten in the form:

$$\langle \mathbf{r} \rangle_s = i \frac{V_a}{(2\pi)^3} \int d\mathbf{k} \langle u_s(\mathbf{r}, \mathbf{k}) | \nabla_{\mathbf{k}} | u_s(\mathbf{r}, \mathbf{k}) \rangle \quad (3.93)$$

$$\langle \mathbf{r}^2 \rangle_s = - \frac{V_a}{(2\pi)^3} \int d\mathbf{k} \langle u_s(\mathbf{r}, \mathbf{k}) | \nabla_{\mathbf{k}}^2 | u_s(\mathbf{r}, \mathbf{k}) \rangle \quad (3.94)$$

where $u_s(\mathbf{r}, \mathbf{k})$ are periodic parts of the Bloch functions defined by (3.89).

The gradient in $\mathbf{k}$ -space, used in (3.93) and (3.94), is correctly defined only in the model of an infinite crystal when a variable $\mathbf{k}$ is continuous. In a cyclic model of a crystal, the gradient of the function is replaced with the approximate finite-differences expressions, and integration on the Brillouin zone is made by summation over a discrete set of wavevectors $\mathbf{k}$. Let $M_{mn}^{(k,b)}$ be defined as the scalar product:

$$M_{s's}^{(k,b)} = \langle u_{s'}(\mathbf{r}, \mathbf{k}) | u_s(\mathbf{r}, \mathbf{k} + \mathbf{b}) \rangle \quad (3.95)$$

where $\mathbf{b}$ is a vector connecting each $\mathbf{k}$ -point from a discrete set, corresponding to the considered cyclic model, with one of its nearest neighbors. Then $\langle \mathbf{r}^2 \rangle_s$ and $\langle \mathbf{r} \rangle_s$ can be approximately calculated using (3.93) and (3.94):

$$\langle \mathbf{r} \rangle_s = - \frac{1}{L} \sum_{\mathbf{k}, \mathbf{b}} w_b \mathbf{b} \operatorname{Im} \ln M_{ss}^{(k,b)} \quad (3.96)$$

$$\langle \mathbf{r}^2 \rangle_s = \frac{1}{L} \sum_{\mathbf{k}, \mathbf{b}} w_b \left\{ \left[1 - |M_{ss}^{(k,b)}|^2 \right] + \left[\operatorname{Im} \ln M_{ss}^{(k,b)} \right]^2 \right\} \quad (3.97)$$

The multiplier w_b depends on the type of Bravais lattice.

Let δU_{rs} be the changes of functional (3.90) value at infinitesimal transformation $\delta U(\mathbf{k})$ of matrices $U(\mathbf{k})$:

$$\delta U_{rs}(\mathbf{k}) = \delta_{rs} + d\Delta_{rs}(\mathbf{k}) \quad (3.98)$$

Here, $d\Delta(\mathbf{k})$ is the antihermitian matrix of infinitesimal transformation. It is possible to show that the gradient of functional (3.91) in the space of matrices U is expressed by the following formula:

$$G(\mathbf{k}) = \frac{dI}{d\Delta(\mathbf{k})} = 4 \sum_b w_b (A \{ R^{(k,b)} \} - S \{ T^{(k,b)} \}) \quad (3.99)$$

where

$$R_{s's}^{(k,b)} = M_{s's}^{(k,b)} [M_{ss}^{(k,b)}]^* \quad (3.100)$$

$$T_{s's}^{(k,b)} = \frac{M_{s's}^{(k,b)}}{M_{ss}^{(k,b)}} (\operatorname{Im} \ln M_{ss}^{(k,b)} + \mathbf{b} \langle \mathbf{r} \rangle) \quad (3.101)$$

and A and S are superoperators:

$$\begin{aligned} A\{B\} &\equiv \frac{B - B^\dagger}{2} \\ S\{B\} &\equiv \frac{B + B^\dagger}{2i} \end{aligned} \quad (3.102)$$

The algorithm of functional (3.90) minimization is based on expression (3.99) and consists in an iterative procedure of the steepest descent. For this purpose, on each iteration the matrix $d\Delta(\mathbf{k})$ is chosen in the form of

$$d\Delta(\mathbf{k}) = \varepsilon G(\mathbf{k}) \quad (3.103)$$

where ε is a positive small constant. As is seen from (3.99), a matrix $G(\mathbf{k})$ is antihermitian ($G^\dagger = -G$), and for this choice the functional change

$$dI = -\varepsilon \sum_{\mathbf{k}} \sum_{ss'} |G_{ss'}(\mathbf{k})|^2 \quad (3.104)$$

is less than zero. Hence, on each step of the iterative procedure, the value of the sum of WF dispersions (3.90) decreases.

Thus, the method consists in a choice of initial approximation to WF and the subsequent iterative procedure of construction as much as possible localized WF (in sense of a minimality of the sum of their dispersions). Subsequently, this method has been advanced and generalized to the case of entangled energy bands [59].

Advantages of the method: the method is universal and can practically be applied for any system; the method is efficient and can be automated to apply in computer code (<http://www.wannier-transport.org>). Disadvantages of the method: in the method, the criterion of localization is fixed as the Boys localization criterion, and therefore, there is no opportunity to receive WF as much as possible localized concerning any another criterion; the symmetry use is not included, and in some cases the number of iterations strongly depends on the initial approximation; and the use of a sufficiently dense grid of wavevectors is necessary to obtain a good accuracy in the gradient calculation.

This method of WF generation is now widely used in PW DFT calculations of Bloch functions. In the next two sections, we consider the LCAO approach to maximally localized WF generation.

3.3.3 *Localized Orbitals for Valence Bands: LCAO Approximation*

The method of the localized WF generation for occupied energy bands was suggested in [51, 60, 61] and implemented with the CRYSTAL code for LCAO

calculations of periodic systems. In this method, WFs are sought in the form of a linear combination of atomic orbitals (AO):

$$W_s(\mathbf{r}) = \sum_{\mu} \sum_n c_{\mu s}^n \phi_{\mu}(\mathbf{r} - \mathbf{s}_{\mu} - \mathbf{a}_n) \quad (3.105)$$

where $\phi_{\mu}(\mathbf{r} - \mathbf{s}_{\mu} - \mathbf{a}_n)$ is the μ th AO, centered in a point $\mathbf{s}_{\mu} + \mathbf{a}_n$; the index s numbers the localized functions in one primitive cell; and $c_{\mu s}^n$ are the coefficients connecting WF and AO. Construction of the localized functions is made by means of an iterative procedure where each step consists of two basic stages.

Let us designate WF after the $(n - 1)$ th step through $W_s^{(n-1)}(\mathbf{r})$. At the first stage, named by authors “Wannierization,” the localized functions $\overline{W}_s^{(n-1)}(\mathbf{r})$ that maximize the functional are sought

$$I_W^{(n)} = \sum_{s=1}^N \left\langle \overline{W}_s^{(n)}(\mathbf{r}) \left| V_s^{(n-1)} \right| W_s^{(n-1)}(\mathbf{r}) \right\rangle \quad (3.106)$$

where the operator $V_s^{(n-1)}$ cuts off the tails of functions $W_s^{(n-1)}(\mathbf{r})$:

$$V_s W_s(\mathbf{r}) = \sum_A p_{A,s} \sum_{\mu \in A} c_{\mu s}^{G_{A,s}} \quad (3.107)$$

Here, index A runs over atoms in a cell; multipliers $p_{A,s}$ are equal to unity only for those atoms on which the Mulliken populations of WF $W_s(\mathbf{r})$ are more than the, fixed in advance, chosen threshold (for other atoms they are supposed to be equal to zero); and the vector $\mathbf{G}_{A,s}$ defines a cell in which this population is maximal. Thus, the application of the operator $V_s^{(n-1)}$ leaves in the sum (3.107) only the members corresponding to atomic functions of one cell and not necessarily over all the atoms of this cell. The renormalization of functions $V_s^{(n-1)} \left| W_s^{(n-1)}(\mathbf{r}) \right\rangle$ makes them, and, hence, the functions $\overline{W}_s^{(n)}(\mathbf{r})$, more localized. To carry out the Wannierization step at the first cycle of the iterative procedure, an initial guess built up from Γ point coefficients in Bloch functions is used in (3.106).

At the second stage termed by “localization,” the linear combination of WF belonging to one cell is searched:

$$W_s^{(n)}(\mathbf{r}) = \sum_{s' \in s} O_{s' s} \overline{W}_{s'}^{(n)}(\mathbf{r}) \quad (3.108)$$

to maximize the functional (similar to that offered by Boys for molecules)

$$I_B^{(n)} = \sum_{s < t} \left[\langle \mathbf{r} \rangle_s^{(n)} - \langle \mathbf{r} \rangle_t^{(n)} \right]^2 \quad (3.109)$$

Here $\langle \mathbf{r} \rangle_s^{(n)}$ is a point of $W_s^{(n)}(\mathbf{r})$ centering (centroid position). In other words, this procedure as much as possible “moves apart” WF centroids positions that promote greater efficiency on the following step of the iterative procedure.

Advantages of the method: the algorithm is efficient and universal, it allows one to construct quickly well-localized WF, and the procedure is completely automated and included in the computer code CRYSTAL. The applications of this method to actual crystals are discussed in Chap. 9. Disadvantages of the method: in this method, it is possible to use only Bloch functions calculated in LCAO approximation (PW-based Bloch functions cannot be used); there is no possibility to apply different localization criteria in WF generation; the Mulliken atomic populations used in the iteration procedure are essentially dependent on the AO basis chosen, and for diffuse AO, they are sometimes unrealistic. The analysis of the basic methods of WF generation shows that though these methods are effective enough, all of them possess those or other disadvantages. It is possible to specify three basic types of these disadvantages:

- (a) WF symmetry is not considered at all, or if it is considered, it is not formulated in the mechanism of definition of this symmetry. It leads, first, to an increase in time of calculations and, secondly, to loss of the control over properties of WF symmetry during their construction.
- (b) The criterion of WF localization ensuring the generation of maximally localized WF is fixed or not defined. In the framework of the same method, it is impossible to compare WF generated for different localization criteria.

An attempt to overcome the disadvantages mentioned was made in [40] where a variational method of Wannier-type function generation was suggested. This method is applicable with the different localization criteria, the Bloch functions can be calculated both in LCAO and in PW basis, and the full symmetry is taken into account. In the next section we consider it in more detail.

3.3.4 Variational Method of Localized Wannier-Function Generation on the Base of Bloch Functions

The background of Wannier-function symmetry analysis is the theory of representations (reps) of a space group G induced from the irreducible representations (irreps) of its site subgroup $G_{\mathbf{q}} \subset G$ called, for brevity, induced representations (indreps). From the theory of indreps of space groups, it follows that the construction of localized functions corresponding to a given simple or composite energy band is possible only if canonical orbitals of this band form the basis of some simple or composite indrep. This analysis permits us not only to establish the principle possibility to construct localized orbitals but also to define the possible positions of their symmetry localization center $\mathbf{q}$ and their symmetry with respect to site-symmetry group $G_{\mathbf{q}}$.

Thus, the symmetry analysis consists of a procedure of identifying localized functions symmetry from the symmetry of the canonical orbitals of the considered energy band, or of establishing the fact that the construction of localized functions is impossible for the reasons of symmetry.

We assume that the canonical orbitals $\varphi_{m\mu}^{(\gamma)}(\mathbf{k}, \mathbf{r}) \equiv \varphi_{\sigma}(\mathbf{k}, \mathbf{r}) \equiv \varphi_s(\mathbf{r})$ (the index m numbers the basis vectors of irrep γ with wavevector $\mathbf{k}$, and μ discriminates between the independent bases of equivalent irreps; the index σ replaces γ, m, μ , and s replaces $\sigma, \mathbf{k}$) of an energy band under consideration form a basis in the space $\mathcal{Q}_{(\mathbf{q}, \beta)}$ of some indrep of the group $G^{(N)}$ of a crystal. The localized functions are defined by a unitary transformation in the space of indrep:

$$W_{ij}^{(\beta)}(\mathbf{r} - \mathbf{a}_n) = N^{-\frac{1}{2}} \sum_{\mathbf{k}} \exp(-i\mathbf{k}\mathbf{a}_n) \psi_{ij}^{(\beta)}(\mathbf{k}, \mathbf{r}) \quad (3.110)$$

or

$$W_{\tau}^{(\beta)}(\mathbf{r} - \mathbf{a}_n) = N^{-\frac{1}{2}} \sum_{\mathbf{k}} \exp(-i\mathbf{k}\mathbf{a}_n) \psi_{\tau}^{(\beta)}(\mathbf{k}, \mathbf{r}) \quad (3.110a)$$

In (3.110), (3.110a) the summation is over the set of N special points in the BZ, which corresponds to the cyclic model considered [53], and the quasi-Bloch functions $\psi_{ij}^{(\beta)}(\mathbf{k}, \mathbf{r}) \equiv \psi_{\tau}^{(\beta)}(\mathbf{k}, \mathbf{r})$ are linear combinations of the canonical orbitals $\varphi_{m\mu}^{(\gamma)}(\mathbf{k}, \mathbf{r}) \equiv \varphi_{\sigma}(\mathbf{k}, \mathbf{r})$ with the same $\mathbf{k}$ belonging to the considered energy band:

$$\psi_{ij}^{(\beta)}(\mathbf{k}, \mathbf{r}) = \sum_{\gamma m \mu} U_{\gamma m \mu, ij}(\mathbf{k}) \varphi_{m\mu}^{(\gamma)}(\mathbf{k}, \mathbf{r}) \quad (3.111)$$

or

$$\psi_{\tau}^{(\beta)}(\mathbf{k}, \mathbf{r}) = \sum_{\sigma} U_{\sigma, \tau}(\mathbf{k}) \varphi_{\sigma}(\mathbf{k}, \mathbf{r}) \quad (3.111a)$$

where $U_{\gamma m \mu, ij}(\mathbf{k}) \equiv U_{\sigma, \tau}(\mathbf{k})$ is a unitary matrix, which, in the case of a nondegenerate band, is reduced to a phase factor $\exp(i\alpha(\mathbf{k}))$. It follows from (3.110) and (3.111)

$$W_{ij}^{(\beta)}(\mathbf{r} - \mathbf{a}_n) = N^{-\frac{1}{2}} \sum_{\mathbf{k}} \sum_{\gamma m \mu} U_{\gamma m \mu, ij}(\mathbf{k}) \cdot \exp(-i\mathbf{k}\mathbf{a}_n) \cdot \varphi_{m\mu}^{(\gamma)}(\mathbf{k}, \mathbf{r}) \quad (3.112)$$

or

$$W_i(\mathbf{r}) = N^{-\frac{1}{2}} \sum_s U_{st} \cdot \varphi_s(\mathbf{r}) \quad \text{with} \quad U_{st} = U_{\gamma m \mu, ij}(\mathbf{k}) \cdot \exp(-i\mathbf{k}\mathbf{a}_n) \quad (3.112a)$$

If the functions $\psi_{ij}^{(\beta)}(\mathbf{k}, \mathbf{r})$ satisfy the conditions of orthonormality

$$\frac{V_a}{(2\pi)^3} \int (\psi_{ij}^{(\beta)}(\mathbf{k}, \mathbf{r}))^* \psi_{i'j'}^{(\beta)}(\mathbf{k}', \mathbf{r}) d\mathbf{r} = \delta_{ii'} \delta_{jj'} \delta(\mathbf{k} - \mathbf{k}') \quad (3.113)$$

the functions $W_{ij}^{(\beta)}(\mathbf{r} - \mathbf{a}_n)$ form an orthonormal system:

$$(W_{ij}^{(\beta)}(\mathbf{r} - \mathbf{a}_n), W_{i'j'}^{(\beta)}(\mathbf{r} - \mathbf{a}_{n'})) = \delta_{ii'} \delta_{jj'} \delta_{nn'} \text{ or } (W_t(\mathbf{r}), W_{t'}(\mathbf{r})) = \delta_{tt'} \quad (3.114)$$

Let $Q_{(\mathbf{q}, \beta)}$ be the space of a simple irrep $(\mathbf{q}, \beta)$ (for simplicity). The space $Q_{(\mathbf{q}, \beta)}$ is spanned by both the set of orthonormal functions $W_{ij}^{(\beta)}(\mathbf{r} - \mathbf{a}_n) \equiv W_t^{(\beta)}(\mathbf{r})$ and the set of Bloch functions $\varphi_{m\mu}^{(\gamma)}(\mathbf{k}, \mathbf{r}) = \varphi_s(\mathbf{r})$; see (3.112). The orthonormal functions $W_t^{(\beta)}(\mathbf{r})$ in (3.112) can be chosen real (if irrep β is real) and transform according to the irrep β of the site groups $L_{\mathbf{q}, n}$ of the points $\mathbf{q}_{j,n}$. Their localization depends on the choice of the matrix $U_{\gamma m\mu, ij}(\mathbf{k})$ in (3.112). The existence of Wannier functions, decreasing exponentially at infinity (for the model of an infinite crystal), is established in many cases. The uniqueness of these functions for nondegenerate bands in crystals with centers of inversion was proved [42, 55]. In this case Wannier functions correspond to a special choice of phase factors $U_{\gamma m\mu, ij}(\mathbf{k}) = \exp(i\alpha(\mathbf{k}))$ of Bloch orbitals $\varphi_{m\mu}^{(\gamma)}(\mathbf{k}, \mathbf{r}) = \varphi_s(\mathbf{r})$ in (3.112). Any other choice of phase factors destroys either the symmetry properties of the Wannier functions or their reality or both [40]. Obviously these functions are as well localized as possible (fall off exponentially in the model of infinite crystal). If the choice of phase factors is not correct, the Wannier functions lose the exponential character of their decrease and, therefore, are not maximally localized according to any reasonable criterion of localization. Unfortunately, the uniqueness of Wannier functions is not yet proved for the more general case of the degenerate bands in crystals with centers of inversion, where it apparently exists.

As a criterion of localization for a localized function $W(\mathbf{r})$, one uses the value of the integral over the whole space of the crystal [40]

$$\mathbf{I} = \int \rho(\mathbf{r}) |W(\mathbf{r})|^2 d\mathbf{r} \quad (3.115)$$

with the weight function $\rho(\mathbf{r}) \geq 0$, which is supposed to be invariant under the operations from the site-symmetry group $G_{\mathbf{q}}$. Particular choices of the weight function are:

1.

$$\rho(\mathbf{r}) = (\mathbf{r} - \mathbf{q})^2 \quad \text{Boys localization criteria.} \quad (3.115a)$$

2.

$$\rho(\mathbf{r}) = \begin{cases} 1, & \text{if } \mathbf{r} \in \Delta; \\ 0, & \text{if } \mathbf{r} \notin \Delta \end{cases} \quad (3.115b)$$

where Δ is some region surrounding the point $\mathbf{q}$ of symmetry localization of the function $W_0^{(\beta)}(\mathbf{r})$.

3.

$$\rho(\mathbf{r}) = (\pi r_o^2)^{-3/2} \exp\left(-\frac{(\mathbf{r} - \mathbf{q})^2}{r_o^2}\right) \quad (3.115c)$$

which underlines the contribution in (3.115) of the values of the function $|W_0^{(\beta)}(\mathbf{r})|^2$ inside the sphere of radius r_o . As a special case of (3.115c) for $r_o \rightarrow 0$ one has $\rho(\mathbf{r}) = \delta(\mathbf{r} - \mathbf{q})$.

One searches for the set of nonorthogonal localized functions $V_{ij}^{(\beta)}(\mathbf{r} - \mathbf{a}_n)$ in the form

$$V_{ij}^{(\beta)}(\mathbf{r} - \mathbf{a}_n) = N^{-\frac{1}{2}} \sum_{\mathbf{k}} \sum_{\gamma\mu} C_{\gamma\mu, ij}(\mathbf{k}) \cdot \exp(-i\mathbf{k}\mathbf{a}_n) \cdot \varphi_{\mu}^{(\gamma)}(\mathbf{k}, \mathbf{r}) \quad (3.116)$$

or

$$V_t^{(\beta)}(\mathbf{r}) = N^{-\frac{1}{2}} \sum_s C_{st} \cdot \varphi_s(\mathbf{r}) \quad (3.116a)$$

The system of functions $V_t^{(\beta)}(\mathbf{r}) \equiv V_{ij}^{(\beta)}(\mathbf{r} - \mathbf{a}_n)$ can be obtained from the function $V_{11}^{(\beta)}(\mathbf{r}) \equiv V_0^{(\beta)}(\mathbf{r})$ in the same way as the functions $W_{ij}^{(\beta)}(\mathbf{r} - \mathbf{a}_n)$ from the function $W_{11}^{(\beta)}(\mathbf{r})$ (see above). Therefore, it is sufficient to find only one function, for example,

$$V_0^{(\beta)}(\mathbf{r}) = N^{-\frac{1}{2}} \sum_s C_{s0} \cdot \varphi_s(\mathbf{r}) \quad (3.117)$$

The coefficients C_{s0} can be found from the following variational problem: to find the coefficients C_{s0} in (3.117), maximizing (or minimizing) the functional (3.115) and satisfying the supplementary condition

$$\int |V_0^{(\beta)}(\mathbf{r})|^2 d\mathbf{r} = 1 \quad (3.118)$$

This variational problem is equivalent to the eigenvalues and eigenvectors problem for the matrix:

$$A_{ss'} = \frac{1}{N} \int \rho(\mathbf{r}) \varphi_s^*(\mathbf{r}) \varphi_{s'}(\mathbf{r}) d\mathbf{r} \quad (3.119)$$

The eigenvalues of the matrix A are stationary values of the localization criterion (3.115), and the eigenvectors corresponding to these values are required coefficients of the expansion (3.117). In our case, it is necessary to search for the eigenvector corresponding to the highest eigenvalue for the choices (3.115b) and (3.115c) of the weight function $\rho(\mathbf{r})$ and to the lowest one for the case (3.115a). Let us note that it is sufficient to use the variational procedure in the subspace of the first basis vectors of the irrep β of the site group L_q instead of the whole space of the canonical orbitals of the energy band under consideration.

Though the set of the functions $V_t(\mathbf{r})$ is not orthogonal, these functions are close to the accurate localized Wannier functions $W_t^{(\beta)}(\mathbf{r}) \equiv W_{ij}^{(\beta)}(\mathbf{r} - \mathbf{a}_n)$. They can be chosen real (for real irrep β of the site group L_q) and satisfy all the symmetry requirements for the functions $W_t^{(\beta)}(\mathbf{r})$. The orthonormal system $\tilde{W}_t^{(\beta)}(\mathbf{r})$ is generated from the functions $V_t^{(\beta)}(\mathbf{r})$ by a suitable symmetrical orthogonalization procedure for periodic systems:

$$\widetilde{W}_t^{(\beta)}(\mathbf{r}) = \sum_{t'} (S^{-\frac{1}{2}})_{t't} V_{t'}^{(\beta)}(\mathbf{r}) \quad (3.120)$$

where S is the overlapping matrix of the functions $V_t^{(\beta)}(\mathbf{r})$:

$$S_{tt'} \equiv (V_t^{(\beta)}(\mathbf{r}), V_{t'}^{(\beta)}(\mathbf{r})) \quad (3.121)$$

Combining (3.116a) and (3.120) we get

$$\widetilde{W}_t^{(\beta)}(\mathbf{r}) = N^{-\frac{1}{2}} \sum_{t's} C_{st'} \cdot (S^{-\frac{1}{2}})_{t't} \cdot \varphi_s(\mathbf{r}) \quad (3.122)$$

As the symmetrical orthogonalization procedure (3.122) leaves unchanged the reality and symmetry properties of the functions, the set of orthonormalized functions $\widetilde{W}_t^{(\beta)}(\mathbf{r})$ satisfies all the requirements to the localized Wannier functions (reality, symmetry requirements, and orthonormality) and (in the case when this set of functions is unique) has to coincide with the latter:

$$\widetilde{W}_t^{(\beta)}(\mathbf{r}) = W_t^{(\beta)}(\mathbf{r}) \quad (3.123)$$

The weight function $\rho(\mathbf{r})$ in the functional **I** (see (3.115)) can be varied. In particular, one can choose for the region Δ in (3.115b) a muffin-tin sphere, some part of a Wigner–Seitz cell (even very small), *etc.* The functions $V_t(\mathbf{r})$ depend on the choice of $\rho(\mathbf{r})$, but, according to calculations, after the procedure of symmetric orthogonalization, we always have the same result even for degenerated bands in crystals with a center of inversion. Apparently, the proposed method gives, in these cases, the orthonormal set of maximally localized Wannier functions. Thus, the numerical calculations imply constructing matrix $A_{ss'}$ (3.119), diagonalizing of this matrix, then obtaining the overlap matrix $S_{tt'}$ (3.121), taking the matrix square root of it and other operations of linear algebra. To demonstrate the reliability of the proposed variational method, let us consider two examples of its applications given in [40]—the Wannier-function generation in silicon and MgO crystals.

In accordance with the theory of induced (band) representations, the corresponding Wannier functions in the silicon crystal (four per unit cell) are centered at the middle of the bonds between the nearest Si atoms (Wyckoff position c with site group $G_c = D_{3d}$) and transform according to the irrep a_{1g} of the site group D_{3d} (see Sect. 3.3.1).

For the variational procedure, two sets of Bloch functions were used (both obtained with the help of CRYSTAL code [21]). The first set (S_1) corresponds to the full electron Hartree–Fock LCAO Calculations; the second one (S_2)—to the pseudopotential Hartree–Fock LCAO method. A model of a finite crystal with periodical boundary conditions (cyclic model) with the main region composed of $4 \times 4 \times 4 = 64$ primitive cells was adopted. The first basis consists of 13s- and

Table 3.17 Localized states for the upper valence band of Si crystal along $[1,1,1]$ direction (the origin is taken in the middle of the bond, x in $a\sqrt{3}/96$ units, a being the conventional lattice constant) [40]

x	$W_1(x)$	$W_8(x)$	$W_{64}(x)$	$W_{64}^{(\text{no})}(x)$
0	-0.2300	-0.2036	-0.1982	-0.1988
3	-0.2190	-0.1975	-0.1926	-0.1930
6	-0.1566	-0.1465	-0.1436	-0.1437
9	0.1204	0.1216	0.1199	0.1196
11	0.4116	0.3840	0.3725	0.3747
12	-0.5831	-0.7333	-0.7579	-0.7406
15	-0.0596	-0.0401	-0.0354	-0.0373
18	0.0497	0.0336	0.0288	0.0307
22	0.0620	0.0501	0.0453	0.0471
27	0.0250	0.0327	0.0317	0.0321
33	-0.0099	0.0097	0.0127	0.0121
39	-0.0098	-0.0002	0.0040	0.0030
45	0.0045	-0.0017	0.0011	0.0004
51	0.0045	-0.0002	0.0006	0.0003
57	-0.0098	0.0005	0.0003	0.0003
63	-0.0099	0.0000	0.0000	-0.0001
69	0.0250	-0.0006	-0.0002	-0.0002
75	0.0649	-0.0015	-0.0002	-0.0001
81	-0.0596	0.0008	0.0000	-0.0001
84	-0.5831	-0.0082	-0.0005	0.0000
87	0.1204	-0.0001	0.0000	0.0000
90	-0.1566	-0.0002	-0.0001	-0.0002
93	-0.2190	-0.0006	-0.0002	-0.0004
96	-0.2300	-0.0008	-0.0003	-0.0006

p -atomic-like functions per atom; the pseudopotential basis consists of $2s$ -, $6p$ -, and $5d$ -functions per atom. The weight function $\rho(\mathbf{r}) = \delta(\mathbf{r} - \mathbf{q})$ has been taken in (3.115).

The bigger the cyclic model of a crystal, the closer are its Wannier functions to those of the model of an infinite crystal. In [40] the convergence of the Wannier functions $W(\mathbf{r})$ (for the set S_1) for different sizes of cubic cells defining the cyclic model of a crystal was studied. The smallest cubic cell consists of four primitive cells; the larger ones consist of 8 and 64 smallest cubic cells. The total number of wavevectors used in BZ summation is four times larger than the number of smallest cubic cells in the supercell. The localized functions $W_1(x)$, $W_8(x)$, $W_{64}(x)$ were calculated according to (3.112) as linear combinations of 4 (supercell coincides with the smallest cubic cell), 32 ($2 \times 2 \times 2 = 8$ cubic cells in a supercell) and 256 ($4 \times 4 \times 4 = 64$ cubic cells in a supercell) Bloch states. Table 3.17

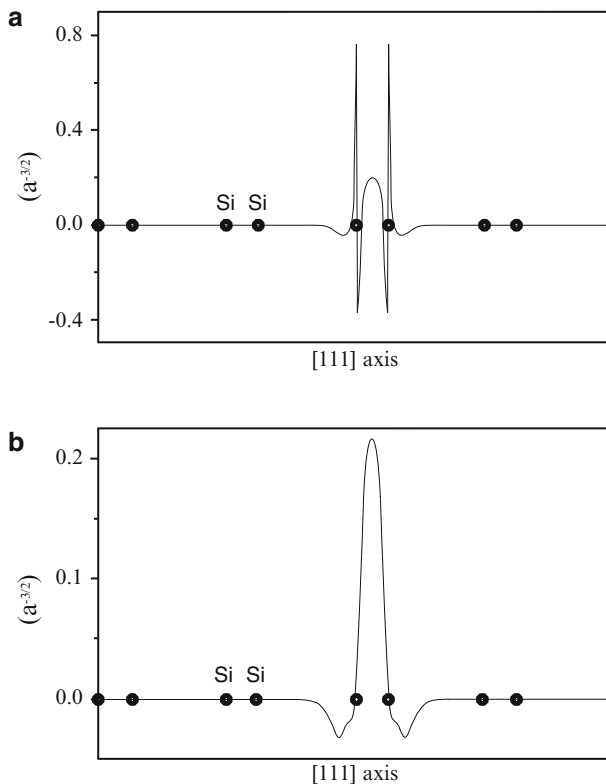


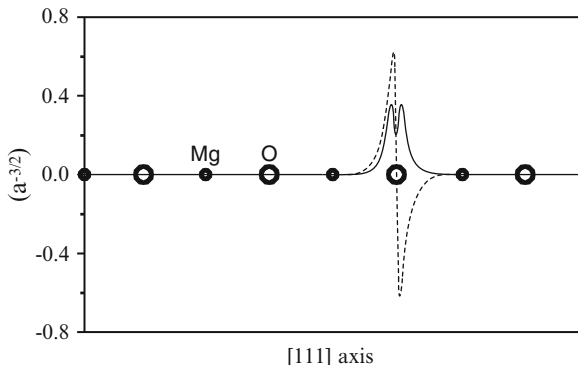
Fig. 3.9 Wannier functions for the silicon upper valence band along the [111] direction: (a) full electron calculation; (b) pseudopotential calculation

gives the values of the Wannier functions $W_1(x)$, $W_8(x)$, $W_{64}(x)$, and $W_{64}^{(no)}(x)$ (the latter is nonorthogonalized) in some points along the $[1, 1, 1]$ direction. As is seen from the table, the function $W_{64}^{(no)}(x)$ is very close to $W_{64}(x)$. So the orthogonalization procedure changes the Wannier function insignificantly. When comparing the functions $W_1(x)$, $W_8(x)$, and $W_{64}(x)$, it is necessary to take into account that these functions are normalized differently, in the volume of 1, 8, and 64 cubic cells, respectively. The fact that their values are relatively close to each other from $x = 0$ to $x = 48$ (in units of $a\sqrt{3}/96$, the translational period in the $[1, 1, 1]$ direction is equal to $a\sqrt{3}$) shows a good localization of the Wannier function under consideration.

Figure 3.9 gives the $W_{64}(x)$ and pseudopotential (pp) Wannier function $W_{64}^{(pp)}(x)$ in the [111] direction.

The functions differ significantly at the atom cores. Outside the cores the behavior of the functions is alike. This is quite natural since the pseudopotential Wannier functions are constructed from smooth pseudowave Bloch functions that are nonorthogonal to the core states. Orthogonalization of these smooth Wannier

Fig. 3.10 Wannier functions for the MgO upper valence band along [111] direction: *solid line* for WF of a_{1g} symmetry, *dotted line*—for one of the three WFs of t_{1u} symmetry



functions to the localized core functions would lead to an increase of oscillations at atom cores observed in the Wannier functions $W_{64}(x)$. The differences between the Wannier functions in the interatomic space are due to the normalization.

In this case, the method reveals a very good stability with respect to the choice of the weight function $\rho(\mathbf{r})$ form. The computations give the same resulting orthogonalized Wannier functions, whereas the intermediate nonorthogonalized functions $V_i(\mathbf{r})$ turn out to be different. An amazing feature was noted. Even if one uses the weight functions, $\rho(\mathbf{r})$ centered at any point in the localization region of the Wannier function, and so the functions $V_i(\mathbf{r})$ do not have the symmetry compatible with the site group $G_{\mathbf{q}}$, the same orthogonalized Wannier functions arise after the symmetrical orthogonalization procedure. The latter not only conserves the symmetry of the localized orbitals but reconstructs(!) it up to an appropriate level. The cause of such flexibility is the fact that the most localized Wannier functions corresponding to a certain energy band are unique and just these functions arise without fail as the result of the proposed variational procedure [40].

To construct the Wannier functions for the upper valence bands of the perfect MgO crystal, a set of MgO Bloch functions has been applied [40] that were obtained in pseudopotential Hartree–Fock LCAO calculations with the CRYSTAL code [21]. The $4 \times 4 \times 4$ cyclic system has been used in the calculations. The valence band of MgO represents two separated bands, and thus, it is possible to construct two independent sets of Wannier functions (for each of the bands). The method of induced representations gives all the Wannier functions being centered on O atoms (Wyckoff position b with site group $G_c = O_h$) and transforming—according to the irrep a_g of the site group O_h for the lower band (one Wannier function per unit cell) and according to the irrep t_{1u} —for the upper band (three Wannier functions per unit cell). The weight function $\rho(\mathbf{r}) = \delta(\mathbf{r} - \mathbf{q})$ was taken in (3.115) located some distance away from the centering point of the corresponding Wannier function—as the Wannier functions of the upper band are antisymmetric and thus equal to zero in their centering points, while, as stated above, the symmetrical centering of $\rho(\mathbf{r})$ function is not necessarily needed.

Figure 3.10 shows the Wannier functions for both the bands in the [111] direction.

The function corresponding to the upper band (dashed curve) is determined up to a linear combination of the three functions transforming via t_{1u} irrep. One can see that both Wannier functions are almost completely localized around one of the oxygen atoms, which confirms the ionic character of MgO compound.

The character of the localization of Wannier functions depends on the analytical properties of Bloch states (as a function of the wavevector) that are essentially determined by the nature of the system under consideration. One can arbitrary change only the form of a unitary transformation of Bloch functions. It is just this arbitrariness that is used in the variational approach [40] to assure the best localization of Wannier functions. The accuracy of the Wannier functions obtained by the proposed method is determined solely by the accuracy of the Bloch functions and the size of the supercell used. As the calculations have shown, the proposed method is reliable and useful in the problem of generation of the localized Wannier functions. In the two examples considered, the Bloch states of only occupied bands were used for WF generation. Inclusion of the vacant band states of the appropriate symmetry allows Wannier-type atomic orbitals (WTAO) to be generated. WTAO are used for the chemical-bonding analysis in crystals. We consider WTAO applications in Chap. 9.

Chapter 4

Hartree–Fock LCAO Method for Periodic Systems

The extension of one-electron approximation (restricted, unrestricted, and restricted open-shell one-determinant Hartree–Fock methods) to periodic systems is discussed. The direct lattice summations in the Fock matrix elements and the $\mathbf{k}$ dependence of the one-electron density matrix, energy levels, and crystalline orbitals are the main difficulties of the HF LCAO method for periodic systems, compared with molecules. A special strategy must be specified for the treatment of the infinite Coulomb and exchange series as well as for the substitution of the integral that appears in density matrix with a weighted sum extended to a finite set of $\mathbf{k}$ -points. In the self-consistent calculations of the electronic structure of crystals both in the basis of plane waves and in the basis of localized atomic-type functions, one needs at every stage of the self-consistent procedure to evaluate an approximate electron-density matrix by integration over the Brillouin zone (BZ), constructing the interpolation formula of the numerical integration based on an interpolation procedure by means of some set of interpolation functions. The nodes for the interpolation ($\mathbf{k}$ -points of the BZ) were called special points of BZ. A one-to-one correspondence is demonstrated between the cyclic system (the supercell) size in the direct lattice and the finite set of wavevectors in the Brillouin zone. It is shown that the supercell (large unit cell–small Brillouin zone) method proves to be the most general and fruitful in practical applications as it gives normally the most efficient sets of special points. An efficient procedure is described for interpolating the density matrix in the BZ. The procedure is based on a detailed analysis of the density-matrix properties in the RHF method for periodic systems.

4.1 One-Electron Approximation for Crystals

4.1.1 One-Electron and One-Determinant Approximations for Molecules and Crystals

The complex quantum-mechanical systems that are molecules and crystals, consisting of a great number of atomic nuclei and electrons, can in many cases be modeled by the nonrelativistic Hamiltonian having the form

$$\hat{H} = -\frac{1}{2} \sum_{i=1}^{2N_e} \Delta_{\mathbf{r}_i} - \frac{1}{2} \sum_{j=1}^{N_a} \frac{1}{M_j} \Delta_{\mathbf{R}_j} + V(\mathbf{r}, \mathbf{R}) \quad (4.1)$$

where $\mathbf{r}_i$ are the coordinates of electrons ($i = 1, 2, \dots, 2N_e$), $\mathbf{R}_j$ are the coordinates of nuclei ($j = 1, 2, \dots, N_a$), and $V(\mathbf{r}, \mathbf{R})$ is the energy of the Coulomb interaction of electrons and nuclei:

$$V(\mathbf{r}, \mathbf{R}) = \sum_{j < j'} \frac{Z_j Z_{j'}}{|\mathbf{R}_j - \mathbf{R}_{j'}|} + \sum_{i < i'} \frac{1}{|\mathbf{r}_i - \mathbf{r}_{i'}|} - \sum_{ij} \frac{Z_j}{|\mathbf{r}_i - \mathbf{R}_j|} \quad (4.2)$$

The Hamiltonian (4.1) is approximate as it does not take into account the spin-orbit interaction and other relativistic effects. The calculation of eigenfunctions and eigenvalues of the operator (4.1), *that is*, the solution of the time-independent Schrodinger equation

$$\hat{H}\Phi = E\Phi \quad (4.3)$$

is possible only after applying some approximations. The first of them is the adiabatic approximation. It permits the motion of electrons and nuclei to be considered separately and is based on the large difference in electron and nuclear masses ($m_e \ll M_j$).

In the adiabatic approximation, first, the problem of electronic motion is solved for fixed positions of nuclei:

$$\left[-\frac{1}{2} \sum_{i=1}^{2N_e} \Delta_{\mathbf{r}_i} + V(\mathbf{r}, \mathbf{R}) \right] \psi(\mathbf{r}, \mathbf{R}) = W(\mathbf{R}) \psi(\mathbf{r}, \mathbf{R}) \quad (4.4)$$

The wavefunctions $\psi(\mathbf{r}, \mathbf{R})$ and the eigenvalues $W(\mathbf{R})$ in (4.4) depend on the nuclear coordinates $\mathbf{R}$ as parameters. Then, the found eigenvalues $W(\mathbf{R})$ are used as the operators of potential energy in the equation determining the nuclear motion:

$$\left[-\frac{1}{2} \sum_{j=1}^{N_a} \frac{1}{M_j} \Delta_{\mathbf{R}_j} + W(\mathbf{R}) \right] \chi(\mathbf{R}) = \varepsilon \chi(\mathbf{R}) \quad (4.5)$$

This way of solving (4.3) is equivalent to the representation of the wavefunction Φ in the form of the product

$$\Phi(\mathbf{r}, \mathbf{R}) = \psi(\mathbf{r}, \mathbf{R})\chi(\mathbf{R}) \quad (4.6)$$

Further corrections of this reasonable approximation may be obtained from adiabatic perturbation theory by using, as the small parameter, the value $(\frac{1}{M})^{1/4}$ where M is the average mass of the nuclei. Equation (4.4) is often considered as an independent problem without any relation to the more general problem (4.3). This is motivated by the following reasoning. If the temperature is not very high, the nuclei vibrate about some equilibrium positions $\mathbf{R}^{(0)}$. Thus, in calculating the electronic structure, only the configuration with the nuclei fixed at their equilibrium positions $\mathbf{R}^{(0)}$ is considered. The latter are typically known from experimental data (*e.g.*, from X-ray or neutron-scattering crystallographic data). This means that electronic-structure calculation without using any other experimental data (except the equilibrium positions of nuclei) is often considered as made from first principles. Often, the first-principle calculations are made with the geometry optimization when the positions of nuclei are found from the total energy minimization. Formally, the results of such calculations correspond to zeroth temperature. We write the equation for the electronic function of the system in the form

$$\hat{H}_e\psi = \left[\sum_i \hat{H}_0(\mathbf{r}_i) + \sum_{i,i'} \frac{1}{|\mathbf{r}_i - \mathbf{r}_{i'}|} \right] \psi = E\psi \quad (4.7)$$

where

$$\hat{H}_0(\mathbf{r}_i) = -\frac{1}{2}\Delta_{\mathbf{r}_i} - \sum_j \frac{Z_j}{|\mathbf{r}_i - \mathbf{R}_j^{(0)}|} + \sum_{j < j'} \frac{Z_j Z_{j'}}{|\mathbf{R}_j^{(0)} - \mathbf{R}_{j'}^{(0)}|} \quad (4.8)$$

We assume here that there are a finite number of electrons in the system. This is certainly true for molecules, but for crystals, it implies that we are using the model of a finite but boundless crystal (cyclic model), *that is*, we consider the bulk of a crystal with cyclic boundary conditions imposed on opposite sides. The Hamiltonian $\hat{H}_e$, being an operator acting on the functions depending on the electron coordinates $\mathbf{r}_i$, is invariant under symmetry operations transforming the nuclear equilibrium configuration into itself. Later, we call it the symmetry group of a crystal. Equation (4.7) is still very complex. Its solution is not yet possible without further simplifying approximations. The variables (electron coordinates) cannot be separated in (4.7) because of the terms describing the mutual Coulomb repulsion between electrons. This is why the exact many-electron wavefunction ψ may not be represented as a product (or the finite sum of products) of one-electron functions. However, the approximate wavefunction $\tilde{\psi}$ may be taken as a sum of the products of one-electron functions, which have to be chosen so that the approximate function $\tilde{\psi}$ is as close as possible to the exact solution ψ .

The Hamiltonian $\hat{H}_e$ does not contain the spin operators. Therefore, the one-electron functions may be expressed in the form of the product $\varphi(\mathbf{r}_i)\alpha_{\pm}(\sigma_i)$ of functions $\varphi(\mathbf{r}_i)$ depending on the spatial coordinates of electrons and functions $\alpha_{\pm}(\sigma_i)$ depending on spin variables only (α, β notations are also used for $\alpha_{\pm}(\sigma_i)$). The function ψ has to be antisymmetric under the exchange of any pair of electrons. This requirement is satisfied by the antisymmetric product of one-electron functions

$$\psi = [(2N_e)!]^{-1/2} \det [\varphi_1(\mathbf{r}_1)\alpha_+(\sigma_1) \dots \varphi_{N_e}(\mathbf{r}_{N_e})\alpha_-(\sigma_{N_e})] \quad (4.9)$$

The function ψ has to transform according to one of the irreps of the symmetry group G (point group for molecules or space group for crystals). We restrict ourselves to calculation of the ground state of the system. The latter is assumed to be invariant under the elements of the symmetry group G and to correspond to a total spin equal to zero. In this case, the wavefunction may be written in the form of a single determinant (one-determinant approximation).

In the Hartree–Fock method (also known as the one-electron approximation or self-consistent field (SCF) method), the system of equations for one-electron functions is obtained from the variational principle minimizing the functional

$$E = \int \psi^* \hat{H}_e \psi d\tau \quad (4.10)$$

provided

$$\int \varphi_i^*(\mathbf{r})\varphi_{i'}(\mathbf{r})d\mathbf{r} = \delta_{ii'} \quad (4.11)$$

The supplementary conditions (4.11) are not the primary restriction of generality. Indeed, the orthogonalization procedure of one-electron functions may be fulfilled directly in the determinant (4.9) without any change in its value. The same condition (4.11) assures the normalization of the function to 1. The one-electron functions satisfy the following system of Hartree–Fock equations:

$$\hat{F}\varphi_i(\mathbf{r}) = \sum_{i'} \varepsilon_{i'i} \varphi_{i'}(\mathbf{r}) \quad (4.12)$$

or

$$\hat{F}\varphi_i = \varphi_i \varepsilon \quad (4.13)$$

where the Hartree–Fock operator

$$\hat{F} = \hat{H}_0 + \hat{J} - \hat{K} \quad (4.14)$$

is defined below, φ is a row of functions φ_i , and ε is the matrix of coefficients $\varepsilon_{i'i}$.

In the Hartree–Fock operator $\hat{F}$, the term $\hat{H}_0$ is the one-electron operator (4.8). The action on the function $\varphi_i(\mathbf{r})$ of the Coulomb operator $\hat{J}$ and exchange operator $\hat{K}$

is determined in the following way. Denote by $\rho(\mathbf{r}, \mathbf{r}')$ the mixed electron density with fixed spin (spinless electron-density matrix):

$$\rho(\mathbf{r}, \mathbf{r}') = \sum_{i=1}^{N_e} \varphi_i(\mathbf{r}) \varphi_i^*(\mathbf{r}') = \varphi(\mathbf{r}) \varphi^\dagger \quad (4.15)$$

where $\varphi^\dagger$ is the column of functions $\varphi_i^*(\mathbf{r}')$. Then

$$\hat{J}\varphi_i(\mathbf{r}) = 2 \int \frac{\rho(\mathbf{r}', \mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r}' \varphi_i(\mathbf{r}) \quad (4.16)$$

$$\hat{K}\varphi_i(\mathbf{r}) = \int \frac{\rho(\mathbf{r}, \mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} \varphi_i(\mathbf{r}') d\mathbf{r}' \quad (4.17)$$

The operator $\hat{J}$ is the potential energy operator of an electron in the Coulomb field created by all the electrons of the system, with the electron in question included. This is a normal multiplication operator. It acts on the functions depending on the space coordinates of an electron. The Coulomb operator is determined if the electron density $\rho(\mathbf{r}', \mathbf{r}')$ is known. The operator $\hat{K}$ is an integral nonlocal operator with the nucleus $\rho(\mathbf{r}, \mathbf{r}')/|\mathbf{r} - \mathbf{r}'|$. To calculate the function $\hat{K}\varphi_i$, it is necessary to know the function values in the entire domain of its determination. The operator $\hat{F}$ (4.14) is self-adjoint, as $\rho(\mathbf{r}, \mathbf{r}') = \rho^*(\mathbf{r}', \mathbf{r})$.

Multiplying both sides of (4.12) by $\varphi_j^*(\mathbf{r})$, integrating over $d\mathbf{r}$, and using the orthonormality of the functions $\varphi_i^*(\mathbf{r})$, we obtain

$$\varepsilon_{ji} = \int \varphi_j^* \hat{F} \varphi_i d\mathbf{r} = \left(\int \varphi_j^* \hat{F} \varphi_i d\mathbf{r} \right)^* = \varepsilon_{ij}^* \quad (4.18)$$

The matrix ε in (4.18) is Hermitian. It may be diagonalized with the help of a unitary transformation U :

$$\hat{F}(\varphi U) = \varphi \varepsilon U = (\varphi U)(U^{-1} \varepsilon U), \quad (4.19)$$

where $U^{-1} \varepsilon U$ is a diagonal matrix. The unitary transformation U ($UU^\dagger = 1$) does not change the electron-density matrix

$$\rho(\mathbf{r}, \mathbf{r}') = \varphi(\mathbf{r}) \varphi^\dagger(\mathbf{r}') = \varphi U U^\dagger \varphi^\dagger = (\varphi U)(\varphi U)^\dagger \quad (4.20)$$

Then, this transformation keeps the Coulomb $\hat{J}$ and exchange $\hat{K}$ operators invariant (and the total $\hat{F}$). Therefore, without any restriction on the generality, the matrix ε in the right-hand side of (4.13) may be considered as diagonal:

$$\hat{F}\varphi_i = \varepsilon_i \varphi_i \quad (4.21)$$

The system of Hartree–Fock equations (4.21) is nonlinear. To solve it, an iterative method is usually used. In the course of the p th iteration, the electron-density matrix $\rho^{(p)}(\mathbf{r}, \mathbf{r}')$ and hence the operators $\hat{J}$ and $\hat{K}$ are considered to be fixed. The system (4.21) then transforms into one linear equation with a fixed self-adjoint operator

$$\hat{F}^{(p)} = \hat{H}_0 + \hat{J}^{(p)} - \hat{K}^{(p)} \quad (4.22)$$

The eigenstates of this operator corresponding to the lower eigenvalues are populated with electrons. The occupied states are used to construct $\rho^{(p+1)}(\mathbf{r}, \mathbf{r}')$ according to (4.20) and then $\hat{J}^{(p+1)}$ and $\hat{K}^{(p+1)}$ according to (4.16) and (4.17). Then, the subsequent iteration is performed. The procedure of solution is stopped when the functions $\varphi_j^{(p)}$ approach $\varphi_j^{(p-1)}(\mathbf{r})$ (within the desired accuracy). In practice, other criteria are also used to estimate the accuracy of the obtained solution (total energy, electron-density convergence criteria).

Thus, by an iterative method, a self-consistent solution of the nonlinear equations (4.21) may be obtained. The rate of convergence of the iterative procedure depends on the nature of the physical system as well as on the choice of the initial approximation.

The calculation of the eigenfunctions of the operator $\hat{F}$ during the p th iteration is itself a difficult problem that may be solved only approximately. To simplify it, the nonlocal exchange potential $\hat{K}$ is often replaced by a local potential. The one possible form of the local exchange potential is (especially for crystals)

$$\hat{K}\varphi_i = -3\alpha \left[(3/4\pi)\rho(\mathbf{r}, \mathbf{r})^{1/3} \right] \varphi_i \quad (4.23)$$

proposed by Slater. The constant α in crystal electronic-structure calculations is an adjustable parameter. The widely used local-density approximation (LDA) is considered in Chap. 7. If no iterative procedure is performed, the electron structure obtained is said to be nonself-consistent. This kind of calculation is justified only when the one-electron Hamiltonian $\hat{F}^{(0)}$ correctly reflects the main features of the exact (self-consistent) energy operator. It is very difficult to guess such a potential without involving some empirical data. The sum of atomic (or ionic) potentials is the simplest and most natural form of the molecular or crystal potential in nonself-consistent calculations. It is also used as an initial approximation in self-consistent electronic-structure calculations. The one-electron Hamiltonian approximation using the LCAO form of crystalline orbitals is known as the tight-binding (TB) method. This nonself-consistent approach was popular in the 1970s when the self-consistent Hartree–Fock calculations were possible only for simple crystals. At the present time, the TB scheme is mainly used as the interpolation scheme: LCAO Hamiltonian parameters are found by fitting to the band structure calculated self-consistently, for example, using a plane-waves basis. Comparing calculation schemes of molecular quantum chemistry with those of quantum chemistry of solids one can say that the TB scheme is a semiempirical extended Hückel theory with periodical boundary conditions. The considered one-electron and one-determinant approximations are applied both for molecules and crystals. The symmetry of

the one-electron Hamiltonian in both cases coincides with the symmetry of the nuclei configuration only for the case of closed-shell molecules or nonconducting crystalline solids. This is shown in next section.

4.1.2 Symmetry of the One-Electron Approximation Hamiltonian

The many-electron Hamiltonian $\hat{H}_e$ in (4.7), acting in the space of functions depending on the coordinates of all the electrons, is invariant under the operators $\hat{g}$ of the equilibrium nuclear configuration symmetry group G . The operators of electron kinetic energy in (4.8) and the Coulomb repulsion between electrons in (4.7) remain unchanged under any transformation belonging to the point- or space-group operations since, according to the definition, the elements of these groups are the transformations that do not change the distances between any two points of the space. As to the operators of electron–nuclear interaction in (4.8), the operations $\hat{g}$ permute the members of the sum, leaving the sum as a whole invariant. Indeed, the coordinate $\mathbf{r}_i$ transforms under g in

$$\mathbf{r}'_i = g\mathbf{r}_i \quad (4.24)$$

and the denominator in (4.8) becomes equal to

$$|\mathbf{r}'_i - \mathbf{R}_j^{(0)}| = |g\mathbf{r}_i - \mathbf{R}_j^{(0)}| = |g(\mathbf{r}_i - g^{-1}\mathbf{R}_j^{(0)})| = |\mathbf{r}_i - g^{-1}\mathbf{R}_j^{(0)}| \quad (4.25)$$

that is, to the denominator of other members in the sum in (4.8). This reasoning also proves the invariance of the one-electron operator $\hat{H}_0$ (4.8) under the transformations g from the group G .

The set of one-electron functions transforming according to the n_β –dimensional irrep $D^{(\beta)}$ is called the shell. For molecules, these shells are connected with irreps of the point-symmetry group. For a crystal, $\beta = (*\mathbf{k}, \gamma)$ —full irreducible representation of space group G , defined by the star of wavevector $*\mathbf{k}$ and irrep γ of the point group of this vector. Taking into consideration the spin states $\alpha_\pm(\sigma)$, we have $2n_\beta$ one-electron states in the shell. The functions $\varphi_i^{(\beta)}(\mathbf{r})\alpha_\pm(\sigma)$ span the space of the rep $D^{(\beta)} \times D^{1/2}$, where $D^{1/2}$ is the rep according to which the spin functions transform. For the systems with closed shells (molecules in the ground state and nonconducting crystals), the determinant (4.9) consisting of the functions of filled shells describes the state invariant under the operations of the group G (transforms over unity irrep of G). In fact, any transformation of G replaces the columns of the determinant by their linear combinations, which does not change the value of the determinant, that is, does not change the many-electron wavefunction ψ . In the case of open-shell systems (molecular radicals or metallic solids), the ground state of the system is described by a linear combination of determinants, appearing under the symmetrization over the identity irrep of group G .

For crystals, the one-determinant approximation is practically the only way to make the electronic-structure calculations.

Now, we check that for the closed-shell systems, the group G is a symmetry group of the Hartree–Fock equations (4.21). First, we note that the sum

$$\sum_{i=1}^{n_\beta} [\varphi_i^{(\beta)}(\mathbf{r}')]^* \varphi_i^{(\beta)}(\mathbf{r}) \quad (4.26)$$

is invariant under the group G , *that is*, transforms over identity irrep of G . This follows from the well-known property for finite groups of the direct product of irreps $D^{(\beta)} \times [D^{(\beta)}]^*$. The electron-density matrix $\rho(\mathbf{r}, \mathbf{r}')$ is also invariant under G because for filled shells, it is the sum of terms like (4.26):

$$\rho(g\mathbf{r}, g\mathbf{r}') = \rho(\mathbf{r}, \mathbf{r}') \quad (4.27)$$

The operators $\hat{F}$ (4.21) and $\hat{F}^{(p)}$ (4.22) are one electron, *that is*, they are determined in the space of functions depending on the coordinates of one electron.

The invariance of the operator $\hat{H}$ is already proved. For Coulomb $\hat{J}$ and exchange $\hat{K}$ operators and for an arbitrary function $\varphi(\mathbf{r})$, we have

$$\begin{aligned} \hat{g}\hat{J}\varphi(\mathbf{r}) &= 2 \int \frac{\rho(\mathbf{r}', \mathbf{r}')}{|g^{-1}\mathbf{r} - \mathbf{r}'|} d\mathbf{r}' \varphi(g^{-1}\mathbf{r}) \\ &= 2 \int \frac{\rho(g^{-1}\mathbf{r}', g^{-1}\mathbf{r}')}{|g^{-1}\mathbf{r} - g^{-1}\mathbf{r}'|} d(g^{-1}\mathbf{r}') \varphi(g^{-1}\mathbf{r}) \\ &= 2 \int \frac{\rho(\mathbf{r}', \mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r}' \varphi(g^{-1}\mathbf{r}) = \hat{J}\hat{g}\varphi(\mathbf{r}) \end{aligned} \quad (4.28)$$

$$\begin{aligned} \hat{g}\hat{K}\varphi(\mathbf{r}) &= \int \frac{\rho(g^{-1}\mathbf{r}, \mathbf{r}')}{|g^{-1}\mathbf{r} - \mathbf{r}'|} \varphi(\mathbf{r}') d\mathbf{r}' \\ &= \int \frac{\rho(\mathbf{r}', \mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} \varphi(g^{-1}\mathbf{r}') d\mathbf{r}' = \hat{K}\hat{g}\varphi(\mathbf{r}) \end{aligned} \quad (4.29)$$

The relation (4.27) and the equality $|g^{-1}\mathbf{r} - g^{-1}\mathbf{r}'| = |\mathbf{r} - \mathbf{r}'|$ and $d(g^{-1}\mathbf{r}') = d\mathbf{r}'$ are used to prove the invariance of $\hat{F}$. As (4.28) and (4.29) hold for an arbitrary function $\varphi(\mathbf{r})$,

$$\hat{g}\hat{J} = \hat{J}\hat{g}, \quad \hat{g}\hat{K} = \hat{K}\hat{g} \quad (4.30)$$

and therefore,

$$\hat{g}\hat{F} = \hat{F}\hat{g}, \quad \hat{g}\hat{F}^{(p)} = \hat{F}^{(p)}\hat{g} \quad (4.31)$$

Thus, the operator $\hat{F}(\hat{F}^{(p)})$ in the electron equation (4.21) has the symmetry group G of the equilibrium nuclear configuration if the electron-density matrix $\rho(\mathbf{r}, \mathbf{r}')[\rho^{(p)}(\mathbf{r}, \mathbf{r}')] is invariant under G . The eigenfunctions of the operator $\hat{F}(\hat{F}^{(p)})$$

form the bases of irreps of G . The invariance of $\rho(\mathbf{r}, \mathbf{r}')[\rho^{(p)}(\mathbf{r}, \mathbf{r}')] is assured for the system with closed shells.$

Thus, taking as the initial approximation that the electron density $\rho^{(0)}(\mathbf{r}, \mathbf{r}')$ is invariant under the group G , we have, during any iteration step and in the self-consistent limit, the one-electron functions classified according to the irreps of the group G —the symmetry group of the equilibrium nuclear configuration.

In the absence of external fields, the realness of the one-electron approximation Hamiltonian is assured at all stages of the self-consistent calculations, at least for a system with closed shells. The realness of the Hamiltonian $\hat{F}^{(p)}$ leads to the real electron-density matrix $\rho^{(p+1)}(\mathbf{r}, \mathbf{r}')$ generated by the eigenfunctions of $\hat{F}^{(p)}$. Indeed, let the functions $\varphi_i^{(\beta)}(\mathbf{r})$ and $(\varphi_i^{(\beta)}(\mathbf{r}))^*$ belong to the same one-electron energy and describe the occupied electron states. If they span the space of the same irrep $D^{(\beta)}$ of G ($D^{(\beta)}$ is real), then the partial sum (4.26) formed by these functions and involved in $\rho^{(p+1)}(\mathbf{r}, \mathbf{r}')$ is obviously real. If they are the independent bases of the irreps $D^{(\beta)}$ and $(D^{(\beta)})^*$ (equivalent or inequivalent), then the sum of two terms of the type (4.26) is also real. This is the case of additional degeneracy due to the Hamiltonian being real. Thus, the electron-density matrix is the sum of real members and is real itself. The real density matrix $\rho^{(p+1)}(\mathbf{r}, \mathbf{r}')$ generates the real Coulomb $\hat{J}^{(p+1)}$ and exchange $\hat{K}^{(p+1)}$ operators and therefore the real one-electron Hamiltonian $\hat{F}^{(p+1)}$ for the $(p + 1)$ th iteration of the self-consistent calculations. The realness of the one-electron approximation Hamiltonian of molecular systems causes additional degeneracy of the energy levels in cyclic point-symmetry groups C_n . In the case of crystals, degenerated energy levels appear corresponding to $\mathbf{k}$ and $-\mathbf{k}$ even for the case when the inversion is absent in the point group F_k . In the next sections, we consider the Hartree–Fock LCAO approach for periodic systems in comparison with that for molecular systems.

4.1.3 *Restricted and Unrestricted Hartree–Fock LCAO Methods for Molecules*

The solution of Hartree–Fock equations without any additional approximations is practically possible only for atoms. Due to the high symmetry of atomic systems, these equations can be solved numerically or by using analytical representation of atomic orbitals (AO). The tables of Roothaan–Hartree–Fock atomic wavefunctions by Clementi and Roetti [62] give atomic functions expanded in terms of Slater-type orbitals with integer quantum numbers. In molecular quantum chemistry, the molecular orbital (MO) is expanded in terms of Gaussian-type orbitals (GTO). Different atomic functions used in calculations of molecules and crystals are considered in Chap. 8. For the moment, we restrict ourselves by representation of MO $\varphi_i(\mathbf{r})$ as a linear combination of atomic orbitals $\chi_{\mu A}(\mathbf{r})$ (MO LCAO approximation):

$$\varphi_i(\mathbf{r}) = \sum_{\mu A} C_{i\mu} \chi_{\mu A}(\mathbf{r}) \quad (4.32)$$

where μ numbers all basis functions centered on atom A and summation is made over all the atoms in the molecular system. The MO LCAO approximation (also known as the Hartree–Fock–Roothaan approximation [63]) is practically the only way to make first-principles calculations for molecular systems. In the standard derivation of the Hartree–Fock equations relative to a closed-shell system, the constraint that each molecular orbital is populated by two electrons or vacant is introduced (restricted Hartree–Fock theory—RHF).

In the MO LCAO approximation, RHF method equation (4.21) transforms to the matrix equations

$$\mathbf{FC} = \mathbf{SCE} \quad (4.33)$$

where $\mathbf{F}$ and $\mathbf{S}$ are the Fock and the overlap matrices and $\mathbf{C}$ and $\mathbf{E}$ are the matrices of eigenvectors and eigenvalues. The dimension M of square matrices $\mathbf{F}$, $\mathbf{S}$, and $\mathbf{C}$ is equal to the number of items in the sum (4.32), *that is*, the total number of AO used in the calculation. The Fock matrix $\mathbf{F}$ is the sum of one-electron $\mathbf{H}$ and two-electron $\mathbf{G}$ parts. The former includes the kinetic (T) and nuclear attraction (Z) energy, the latter is connected with the electron–electron interactions. The matrix elements $H_{\mu\nu}$ are written in the form

$$H_{\mu\nu} = -1/2 \int \chi_{\mu}^*(\mathbf{r}) \nabla_r^2 \chi_{\nu}(\mathbf{r}) dV + \sum_A \int \chi_{\mu}^*(\mathbf{r}) \frac{Z_A}{|\mathbf{r} - \mathbf{R}_A|} \chi_{\nu}(\mathbf{r}) dV = T_{\mu\nu} + Z_{\mu\nu} \quad (4.34)$$

The one-electron matrix $\mathbf{H}$ is independent of the density matrix and therefore does not change during the self-consistent solution of Hartree–Fock–Roothaan equations. The two-electron matrix $\mathbf{G}$ includes Coulomb ($\mathbf{C}$) and exchange ($\mathbf{X}$) parts of interelectron interaction:

$$G_{\mu\nu} = C_{\mu\nu} + X_{\mu\nu} = \sum_{\lambda\sigma} P_{\lambda\sigma} (\mu\nu|\lambda\sigma) - \frac{1}{2} \sum_{\lambda\sigma} P_{\lambda\sigma} (\mu\lambda|\nu\sigma) \quad (4.35)$$

where

$$(\mu\nu|\lambda\sigma) = \int \int \chi_{\mu}^*(\mathbf{r}) \chi_{\nu}^*(\mathbf{r}) |\mathbf{r} - \mathbf{r}'|^{-1} \chi_{\lambda}(\mathbf{r}') \chi_{\sigma}(\mathbf{r}') dV dV' \quad (4.36)$$

are two-electron integrals calculated with basis atomic orbitals. The one-electron kinetic energy and nuclear attraction integrals and two-electron integrals can be calculated at the beginning of solution of these equations and stored in the external memory of a computer. In some cases, this integrals calculation is more efficient at each step of the self-consistent process.

The two-electron part (4.35) contains one-electron density matrix elements

$$P_{\lambda\sigma} = 2 \sum_i C_{i\mu}^* C_{i\nu} \quad (4.37)$$

The one-electron density matrix $\mathbf{P}$ in AO basis is calculated self-consistently after the initial set of coefficients $\mathbf{C}$ is known. The simple one-electron Hamiltonian

of Huckel type is often used as an initial approximation to the Hartree–Fock Hamiltonian. It is important to remember that the one-electron approximation is made when the many-electron wavefunction is written as the Slater determinant or their linear combination. For bound states, precise solution of Schrodinger equation can be expressed as a (in general infinite) linear combination of Slater determinants.

The approximation of the one-electron Hamiltonian is the next step in the framework of the one-electron approximation—the electron–electron interactions are excluded from the Hamiltonian. In solid-state theory, the LCAO one-electron Hamiltonian approximation is known as the tight-binding method. In molecular quantum chemistry, the one-electron Hamiltonians of Hückel or Mulliken–Rüdenberg types (see Chap. 6) were popular in the 1950s and the beginning of the 1960s when the first-principles, Hartree–Fock LCAO calculations were practically impossible.

The total electron energy E_e in the Hartree–Fock LCAO method is calculated from the relation

$$E_e = \frac{1}{2} \sum_{\mu\nu} P_{\mu\nu} (F_{\mu\nu} + T_{\mu\nu} + Z_{\mu\nu}) \quad (4.38)$$

The total energy $E = E_e + E_N$ is the sum of electron energy and nuclear repulsion energy

$$E_N = \sum_{j < j'} \frac{Z_j Z_{j'}}{|\mathbf{R}_j - \mathbf{R}_{j'}|} \quad (4.39)$$

The energy E_N is fixed for fixed nuclei configuration $\{\mathbf{R}_1, \dots, \mathbf{R}_j, \dots, \mathbf{R}_N\}$. When the optimization of molecular atomic configuration is made, the different nuclei configurations are considered to find that which gives the total energy minima. For each such configuration, the self-consistent electron-energy calculation is made. By definition, in the molecular states with closed shells, all MO are fully occupied by electrons (by 2, 4, and 6 electrons for nondegenerated, two- and three-times degenerated irreps of point groups, respectively) or empty. The corresponding many-electron wavefunction can be written as a single Slater determinant, each MO is occupied by an equal number of electrons with α and β spins. Such a function describes the ground state of a molecule with total spin $S = 0$ and with the symmetry of identity representation of the point-symmetry group.

In the case of open-shell molecular systems, a single Slater determinant describes a state with the fixed spin projection (equal to the difference of n_α and n_β electrons) but is not the correct spin eigenfunction. Indeed, let in the open-shell configuration the highest one-electron energy level be occupied by one electron with α spin. As there are no spin interactions in the Hartree–Fock Hamiltonian, the same electron energy corresponds to the function with β -spin electrons on the highest occupied level. This means that in order to get the correct total spin eigenfunction transforming over the identity representation of the point group, it is necessary to use

a sum of Slater DETERMINANTS. The molecules with an odd number of electrons, the radicals, and the magnetic systems have the open shells in the ground state.

The restricted open-shell Hartree–Fock (ROHF) and the unrestricted Hartree–Fock method (UHF) approximations permit, however, open-shell systems to be described while maintaining the simplicity of the single-determinant approximation. This is made at the stage of self-consistent electronic-structure calculations. Afterward, the obtained spin-orbitals can be used to get the correct total spin many-determinant wavefunction and to calculate the corresponding electron energy.

The ROHF [64] many-electron wavefunction is, in the general case, a sum of Slater determinants; each determinant contains a closed-shell subset, with doubly occupied orbitals and an open-shell subset, formed by orbitals occupied by a single electron.

In one particular case, the ROHF wavefunction reduces to a single determinant: this is the so-called half-closed-shell cases, where it is possible to define two sets of orbitals, the first n_d occupied by paired electrons and the second n_s by electrons with parallel spins. The total number of electrons $n = n_d + n_s$. In all molecular programs, ROHF means a single-determinant wavefunction with maximal spin projection that is automatically eigenfunctions of S^2 with the maximal spin-projection value $S = n_s/2$. So, for the ROHF method, projection on a pure spin state is not required. The space symmetry of the Hamiltonian in the ROHF method remains the same as in the RHF method, *that is*, coincides with the space symmetry of nuclei configuration. The double-occupancy constraint allows the ROHF approach to obtain solutions that are eigenfunctions of the total spin operator. The molecular orbitals diagram for the ROHF half-closed shell is given in Fig. 4.1 (left).

In the UHF method, keeping a single-determinant description, the constraint of double occupancy of molecular orbitals is absent as α electrons are allowed to occupy orbitals other than those occupied by the β electrons; see Fig. 4.1 (right). The greater variational freedom allows the UHF method to produce wavefunctions that are energetically more stable, *that is*, give lower electron energy. Another advantage of the UHF method is that it allows solutions with locally nonzero negative or positive spin density (*i.e.*, ferromagnetic or antiferromagnetic systems). However, UHF solutions are formed by a mixture of spin states and are eigenfunctions only of the total spin-projection operator S_z .

In the UHF approach, the single-determinant wavefunction is computed using n_α MOs $\varphi^\alpha(\mathbf{r})$ and n_β MOs $\varphi^\beta(\mathbf{r})$, corresponding to the electrons with α and β spin, respectively. The wavefunction of the system with n electrons ($n = n_\alpha + n_\beta$) has the following form:

$$\Psi = (N!)^{-1/2} \det \{ \varphi_1^\alpha(\mathbf{r}_1)\alpha(1) \dots \varphi_{n_\alpha}^\alpha(\mathbf{r}_{n_\alpha})\alpha(n_\alpha) \\ \varphi_1^\beta(\mathbf{r}_{n_\alpha+1})\beta(n_\alpha+1) \dots \varphi_{n_\beta}^\beta(\mathbf{r}_n)\beta(n) \} \quad (4.40)$$

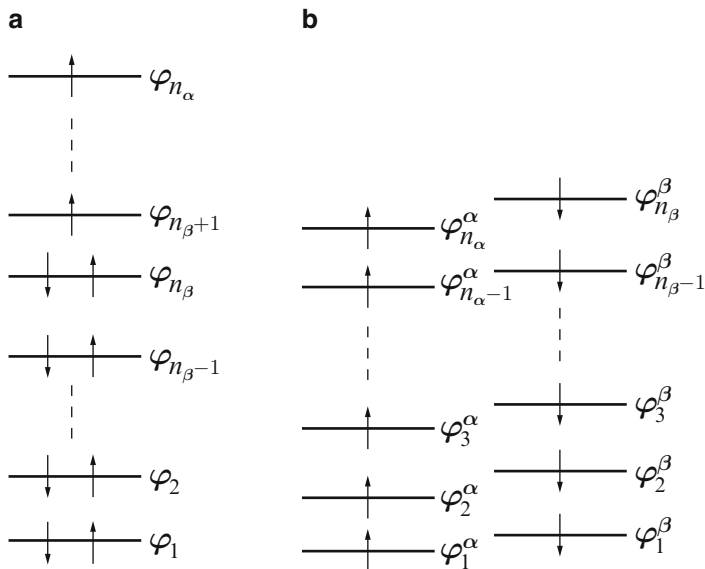


Fig. 4.1 The one-electron levels filling in (a) ROHF and (b) UHF methods

The energy expression is given by the following formula:

$$E = \langle \Psi | \hat{H} | \Psi \rangle = \sum_i \langle \varphi_i^{\alpha} | \hat{H} + 1/2(\hat{J} - \hat{K}^{\alpha}) | \varphi_i^{\alpha} \rangle + \sum_j \langle \varphi_j^{\beta} | \hat{H} - 1/2(\hat{J} - \hat{K}^{\beta}) | \varphi_j^{\beta} \rangle \quad (4.41)$$

where the Coulomb $\hat{J}$ and the exchange $\hat{K}^{\alpha}, \hat{K}^{\beta}$ operators are defined as in the standard RHF equations, that is,

$$\hat{J}(\mathbf{r})\varphi(\mathbf{r}) = \sum_i \left(\int d\mathbf{r}' \varphi_i^*(\mathbf{r}') |\mathbf{r} - \mathbf{r}'|^{-1} \varphi_i(\mathbf{r}') \right) \varphi(\mathbf{r}) \quad (4.42)$$

$$\hat{K}^{\alpha}(\mathbf{r})\varphi(\mathbf{r}) = \sum_i \left(\int d\mathbf{r}' (\varphi_i^{\alpha})^*(\mathbf{r}') |\mathbf{r} - \mathbf{r}'|^{-1} \varphi(\mathbf{r}') \right) \varphi_i^{\alpha}(\mathbf{r}) \quad (4.43)$$

$$\hat{K}^{\beta}(\mathbf{r})\varphi(\mathbf{r}) = \sum_i \left(\int d\mathbf{r}' (\varphi_i^{\beta})^*(\mathbf{r}') |\mathbf{r} - \mathbf{r}'|^{-1} \varphi(\mathbf{r}') \right) \varphi_i^{\beta}(\mathbf{r}) \quad (4.44)$$

In the LCAO approximation, we write now MO for α - and β -spins with different coefficients

$$\varphi_i^{\alpha}(\mathbf{r}) = \sum_{\mu A} C_{i\mu}^{\alpha} \chi_{\mu A}(\mathbf{r}); \quad \varphi_i^{\beta}(\mathbf{r}) = \sum_{\mu A} C_{i\mu}^{\beta} \chi_{\mu A}(\mathbf{r}) \quad (4.45)$$

and introduce the total density $\mathbf{P}^{\text{tot}}$ and spin density matrices $\mathbf{P}^{\text{spin}}$

$$\begin{aligned}\mathbf{P}^{\text{tot}} &= \mathbf{P}^\alpha + \mathbf{P}^\beta, \quad \mathbf{P}^{\text{spin}} = \mathbf{P}^\alpha - \mathbf{P}^\beta \\ \mathbf{P}_{\lambda\sigma}^\alpha &= \sum_i C_{i\lambda}^{\alpha*} C_{i\sigma}^\alpha, \quad \mathbf{P}_{\lambda\sigma}^\beta = \sum_j C_{j\lambda}^{\beta*} C_{j\sigma}^\beta\end{aligned}\quad (4.46)$$

The total density matrix is used to get the expectation value of one-electron operators that are spin independent:

$$\langle \hat{O} \rangle = \sum_\mu \sum_\nu \mathbf{P}_{\mu\nu}^{\text{tot}} \langle \chi_\mu | \hat{O} | \chi_\nu \rangle \quad (4.47)$$

To get the equations for the optimal UHF orbitals, we proceed as in the standard RHF case, we compute the first energy variation, and then we introduce the orthonormality constraint of the basis set by means of the Lagrange multipliers method [65]. The Pople–Nesbet equations

$$\mathbf{F}^\alpha \mathbf{C}^\alpha = \mathbf{S} \mathbf{C}^\alpha \mathbf{E}^\alpha \quad (4.48)$$

$$\mathbf{F}^\beta \mathbf{C}^\beta = \mathbf{S} \mathbf{C}^\beta \mathbf{E}^\beta \quad (4.49)$$

of the UHF LCAO method can be considered as the extension of the RHF LCAO method equations (4.33) to the case when MO occupied by α - and β -spins are varied independently. However, (4.48) and (4.49) cannot be solved independently as the Fock matrix depends not only on the total density $\mathbf{P}^{\text{tot}}$ and has the form

$$\mathbf{F}^\alpha = \mathbf{F} - \frac{1}{2} \mathbf{K}[\mathbf{P}^{\text{spin}}], \quad \mathbf{F}^\beta = \mathbf{F} + \frac{1}{2} \mathbf{K}[\mathbf{P}^{\text{spin}}] \quad (4.50)$$

where the matrices $\mathbf{F}$ and $\mathbf{G}$ are defined as

$$\mathbf{F} = \mathbf{H} + \mathbf{G}; \quad \mathbf{G} = \mathbf{J}[\mathbf{P}^{\text{tot}}] - \frac{1}{2} \mathbf{K}[\mathbf{P}^{\text{tot}}] \quad (4.51)$$

The total electron energy expression now has the form

$$E = Sp \mathbf{P}^{\text{tot}} \mathbf{H} + \frac{1}{2} Sp \mathbf{P}^{\text{tot}} \mathbf{G} - \frac{1}{4} Sp \mathbf{P}^{\text{spin}} \mathbf{K}[\mathbf{P}^{\text{spin}}] \quad (4.52)$$

To solve the UHF method equations, the iterative procedure is necessary as was already discussed for the RHF method. At first, an initial guess at the density matrices $\mathbf{P}^\alpha$ and $\mathbf{P}^\beta$ is made. Then, the Fock matrices $\mathbf{F}^\alpha$ and $\mathbf{F}^\beta$ are calculated from (4.46). The matrices of coefficients $\mathbf{C}^\alpha$ and $\mathbf{C}^\beta$ are determined by diagonalization of the Fock matrices for α - and β -spins, and the density matrix for the next iteration is built. The whole process must be repeated to self-consistency; the convergence criteria consider either the density matrix or the total electron

energy. In order to get spin-polarized solutions from an UHF calculation, it is necessary that the initial density matrices $\mathbf{P}^\alpha$ and $\mathbf{P}^\beta$ are chosen to be different and this difference maintained during the whole SCF process[66]. The RHF closed-shell solution can be considered as a special case of the UHF method, where the number of α electrons coincides with the number of β electrons ($n_\alpha = n_\beta$). In the RHF method, $\mathbf{P}^\alpha = \mathbf{P}^\beta$ for the whole SCF process. In the UHF method (when initial matrices $\mathbf{P}^\alpha \neq \mathbf{P}^\beta$), we could have either spin-polarized solutions at the end of the SCF cycle or the spin polarization will vanish in the course of the SCF process. Reaching a closed-shell solution from a spin-polarized starting point is favored when the latter solution has lower energy.

The extension of the RHF, ROHF, and UHF LCAO methods to periodic systems is considered in the next sections. We begin this consideration from the discussion of specific features of these methods when instead of a molecular system, the cyclic model of a crystal is introduced.

4.1.4 Specific Features of the Hartree–Fock Method for a Cyclic Model of a Crystal

The extension of the HF method to a model of an infinite crystal leads to difficulties connected with the one-electron Bloch functions (BF) behavior since they do not fall off to zero at infinity and therefore cannot be normalized to unity in a space [67]. To overcome this difficulty, periodic boundary conditions (PBC) are introduced for the BF normalized in the main region of volume of the crystal containing a large number N of primitive unit cells of volume.

In the HF method for molecular systems, a many-electron wavefunction in the form of a Slater determinant is written for the system containing a fixed number of electrons. PBC introduction for the infinite crystal allows the system of infinite number of electrons to be replaced by the system of a finite number of electrons (a cyclic cluster). But, in a cyclic cluster containing a large number N of primitive unit cells, the number of electrons remains huge, and from the very beginning, it is necessary to take into account the translation symmetry that is an opportunity to generate a whole cyclic cluster by translations of a primitive unit cell. The concept of the cyclic cluster helps to understand why, on calculation of the Fock matrix for a crystal, it is necessary to make summations on a direct lattice and on the Brillouin zone. Thus, the dimension of the Fock matrix is determined by the number of the basis atomic functions referring not to an infinite crystal or its main region but to its small part—the primitive unit cell.

Let the infinite crystal be replaced with a cyclic system (cyclic cluster) from $N = N_1 \times N_2 \times N_3$ primitive cells, *that is*, replaced with a parallelepiped with edges $N_i \mathbf{a}_i$ ($i = 1, 2, 3$). Periodic boundary conditions mean that opposite sides of a parallelepiped are identified, *that is*, translations on vectors $N_i \mathbf{a}_i$ ($i = 1, 2, 3$) are equivalent to zero translation. The number of electrons in a cyclic system is equal

$N \times n$, where n is the number of electrons on a primitive unit cell. In the HF method, the cyclic system under consideration can be considered as a huge molecular system with periodical boundary conditions imposed on molecular orbitals. The matrix elements of the Fock operator for the cyclic cluster in the LCAO basis have to include the summation on all atoms in the cyclic cluster. To calculate the one-electron density matrix elements, the summation has to be performed on all the molecular orbitals occupied by $N \times n$ electrons. We shall notice that for essentially ionic systems, the cyclic cluster under consideration should be placed in a Madelung field of the rest of an infinite crystal. This means that in the diagonal elements of the Fock matrix, contributions should be added from the field of point charges of those atoms that are not included in the cyclic cluster. With such an approach, interatomic interactions in a crystal are actually separated into short-range and long-range ones. The former are taken into account directly in the cyclic-cluster calculation, the latter are approximated by inclusion of the Madelung field acting on every atom of the cyclic cluster under consideration. The efficient techniques of the Madelung field calculation are developed in the solid-state theory [68], and we do not discuss them here. In [53], the symmetry group of the cyclic model of a crystal was examined, and the connection of this group with the symmetry group of an infinite crystal was discussed. In particular, it was shown that the inner translations of a cyclic system form a subgroup of the translation group of an infinite crystal. This allows calculation of the electronic structure of the cyclic system using the atomic basis symmetrized over the operations of this translation subgroup. This means use of LCAO Bloch functions for those wavevectors that are connected with the group $T^{(N)}$ of inner translations of cyclic system. By this, the Fock matrix is split up into blocks whose dimension is determined by number of different one-dimensional representations of the translation group $T^{(N)}$, *that is*, those nonequivalent wavevectors in the Brillouin zone that correspond to these representations. These wavevectors are defined by the relation $\exp(-ikA) = 1$, where A is the translation vector of the cyclic system as a whole. Comparing the HF method for crystals with that for molecules, we conclude that instead of one the system of HF equations the separate equations for any of nonequivalent wavevectors is necessary to solve at each iteration of the self-consistent procedure. The preliminary atomic basis symmetrization in the Hartree–Fock calculations of molecular systems can also be carried out to split up the Fock matrix into blocks of smaller dimensions. However, the gain of such a splitting, as a rule, is insignificant especially for those point groups that have many dimensional irreducible representations. For a crystal, the direct account of translation symmetry is a unique way to calculate the electronic structure. The summation over a direct lattice in the Fock matrix appears as the sum over atoms included in the cyclic cluster. The use of the translation symmetry allows one to calculate only those matrix elements of the Fock matrix that are connected with the AOs of the reference primitive unit cell (the zero translation vector corresponds to the reference primitive cell). In the density-matrix calculation for a cyclic system, the summation over wavevector appears. This summation means the use of an atomic basis symmetrized over the translation subgroup of a cyclic system symmetry group and replaces the

summation over the occupied MO of a cyclic system by summation over occupied crystalline orbitals for different wavevectors. Their number is determined by the number of electrons in a primitive unit cell. The further splitting of the Fock matrix can be made using the connection between the irreducible representations of the symmetry group of a cyclic system and those of an infinite-crystal symmetry group. For each wavevector, only the one ray of its star can be considered, and summation on a star is carried out by application of operations of the point group of a crystal to that crystalline orbital calculated for this ray. The full space-group symmetry inclusion in the HF LCAO method is considered in [26, 27] and realized in the CRYSTAL code [21]. Naturally, there is a question: what size of a cyclic system is it possible to be limited modeling of each actual crystal? This depends on the character of localization of electronic density in a crystal: in ionic crystals and semiconductors with a large energy gap (5–10 eV), the electronic density is well-enough localized on ions or interatomic bonds so the cyclic system of rather small sizes describes a short-range part of the interatomic interactions. This means that on calculation of the one-electron density for such crystals, it is possible to be limited to summation on a rather small number of points of the Brillouin zone. In crystals with a small energy gap, or metals, the size of the needed cyclic system becomes essentially larger as the one-electron states are more delocalized (in metals, these states are practically delocalized over the whole infinite crystal). Therefore, the summation over the Brillouin zone in calculations of crystals with a small energy gap requires many k -points to be included. We see that one-to-one correspondence between the cyclic system size in direct lattice and the finite set of wavevectors in the Brillouin zone allows an investigation of the convergence of the results of electronic-structure calculations on the size of the cyclic system sufficient to describe short-range interatomic interactions in a crystal. Nevertheless, such an investigation is made by the primitive unit-cell calculations. In the next sections, we consider in more detail the HF LCAO method for periodic systems.

4.1.5 *Restricted Hartree–Fock LCAO Method for Crystals*

The reformulation of Hartree–Fock LCAO molecular equations (4.33) to make them suitable for periodic systems was proposed in [71] about 40 years ago. However, the first HF LCAO calculations were made mainly for the simple solids [69] or for one-periodic systems (polymers)[70, 71] in which the direct lattice summations are essentially simpler than in the two- or three-periodic systems. The periodic HF LCAO method for the systems with any periodicity (polymers, surfaces, bulk crystals) was implemented in the CRYSTAL code [21] after the detailed theoretical study of the exact-(nonlocal) exchange Hamiltonian for the periodic systems. The following main aspects were examined [72]: (a) the point and translational symmetry properties of the HF LCAO Hamiltonian and the transformation of all relevant monoelectronic and bielectronic terms under the symmetry operators,

(b) the use of general yet powerful criteria for the truncation of infinite sums of Coulomb and exchange integrals, and (c) the use of a procedure for performing integrals over wavevector $\mathbf{k}$ as needed in the reconstruction of the Fock matrix in the SCF calculation. The first successful applications of the CRYSTAL code to the calculations of the ground-state properties of the two-periodic [73] (hexagonal boron nitride) and three-periodic [74] (cubic boron nitride and silicon) have opened a more than 25-year ab initio HF LCAO study of the bulk electronic properties of crystals, both perfect and defective, the extension of the method to the surface modeling and magnetic systems. The density functional theory (DFT) LCAO and hybrid (HF-DFT) calculation schemes were implemented in the later versions of the CRYSTAL code [75]. The next step was made when the EMBED code [76] appeared with the implementation of the perturbed-cluster model of point defects in crystals. The detailed discussion of many results obtained by HF and DFT LCAO methods we postpone until Chaps. 9–11. The reader interested in the list of the actual systems calculations is referred to the Internet sites <http://www.crystal.unito.it> and <http://www.cse.clrc.ac.uk>. Recently, periodic boundary conditions were included in the molecular code Gaussian [77], and the first-principles HF and DFT calculations were made with the use of this code [78]. In Appendix C, we give brief information about these two and some other HF and DFT LCAO computer codes for crystals.

In this section, we examine the main modifications in the Hartree–Fock–Roothaan equations (4.33), it being necessary to take into account the translation symmetry of periodic systems. The first most important difference appears in the LCAO representation of the crystalline orbitals (CO) compared to the molecular orbitals (MO).

For the periodic system, the AO symmetrization over the translation subgroup of the space group is made giving the Bloch sums of AOs:

$$\chi_{\mu\mathbf{k}}(\mathbf{r}) = \frac{1}{\sqrt{N}} \sum_{\mathbf{R}_n} \exp(i\mathbf{k} \cdot \mathbf{R}_n) \chi_{\mu}(\mathbf{r} - \mathbf{R}_n) \quad (4.53)$$

In (4.53), the index μ labels all AOs in the reference primitive unit cell ($\mu = 1, 2, \dots, M$), and $\mathbf{R}_n$ is the translation vector of the direct lattice (for the reference primitive cell $\mathbf{R}_n = 0$). The summation in (4.53) is supposed to be made over the infinite direct lattice (in the model of the infinite crystal) or over the inner primitive translations $\mathbf{R}_n^0$ of the cyclic cluster (in the cyclic model of a crystal). In the latter case, the sum of the two inner translation vectors $\mathbf{R}_n^0 + \mathbf{R}_m^0 = \mathbf{R}_l$ may appear not to be the inner translation of the cyclic cluster. However, the subtraction of the translation vector $\mathbf{A}$ of the cyclic cluster as a whole (in the cyclic model, the vector $\mathbf{A}$ is supposed to be equivalent to the zero translation) gives the inner translation again: $\mathbf{R}_l^0 = \mathbf{R}_l - \mathbf{A}$.

The Bloch sum of AO (4.53) satisfies the Bloch theorem. To check this, let us apply the translation operator $\hat{t}_{\mathbf{R}_m}$ (for the fixed translation $\mathbf{R}_m$) to the sum (4.53):

$$\begin{aligned}
\hat{t}_{\mathbf{R}_m} \chi_{\mu \mathbf{k}}(\mathbf{r}) &= \chi_{\mu \mathbf{k}}(\mathbf{r} - \mathbf{R}_m) \\
&= \exp(-i\mathbf{k} \mathbf{R}_m) \frac{1}{\sqrt{N}} \sum_{\mathbf{R}_n} \exp(i\mathbf{k}(\mathbf{R}_n + \mathbf{R}_m)) \chi_{\mu}(\mathbf{r} - \mathbf{R}_m - \mathbf{R}_n) \\
&= \exp(-i\mathbf{k} \mathbf{R}_m) \sum_{\mathbf{R}_{n'} = \mathbf{R}_n + \mathbf{R}_m} \exp(i\mathbf{k} \mathbf{R}_{n'}) \chi_{\mu}(\mathbf{r} - \mathbf{R}_{n'}) \\
&= \exp(-i\mathbf{k} \mathbf{R}_m) \chi_{\mu}(\mathbf{r})
\end{aligned} \tag{4.54}$$

The replacing of the sum over translation vectors $(\mathbf{R}_n + \mathbf{R}_m)$ by the sum over translation vectors $\mathbf{R}_{n'}$ is evidently possible for the infinite crystal. In the cyclic cluster, this replacement means the subtraction of the translation vector $\mathbf{A}$.

In the LCAO approximation, CO is the Bloch function as it is expanded over the Bloch sums of AOs:

$$\varphi_{i\mathbf{k}}(\mathbf{r}) = \sum_{\mu} C_{i\mu}(\mathbf{k}) \chi_{\mu \mathbf{k}}(\mathbf{r}) \tag{4.55}$$

In the MO LCAO approximation, the index i in the expansion (4.32) numbers the MOs (their total number M is equal to the number of atomic orbitals used in the expansion (4.32)). In the case of closed shells, the N_e electrons of the molecule occupy $N_e/2$ MOs, and $(M - N_e/2)$ MOs are empty. The total number of COs of the cyclic cluster equals $M \times N$ (N is the number of the primitive unit cells in the cyclic cluster; M is the number of AO basis functions per primitive unit cell). For the cyclic cluster containing $N_e = N \times n$ electrons (n is the number of electrons per primitive unit cell), $N_e/2$ crystalline orbitals are occupied by electrons, and $(M \times N - N_e/2)$ orbitals are empty. The numbering of crystalline orbitals is made by two indices i and $\mathbf{k}$: the one-electron states of a crystal form the energy bands numbered by index i and joining the N states with the same i . The closed-shell case (the nonconducting crystals) means that all the energy bands are filled or empty (there are no partly filled energy bands). For $N \rightarrow \infty$, the total number of COs also becomes infinite, and the one-electron energy levels form the continuous energy bands, but the total number of energy bands remains finite and is equal to M . For the closed-shell case, $n/2$ electrons occupy the lowest-energy bands for each $\mathbf{k}$ -vector. As discussed in Sect. 3.2.5, MgO and Si crystals are examples of nonconducting systems with different values of the forbidden energy gap (Figs. 3.4–3.5). The latter is the crystalline analog of the HOMO (highest-occupied MO)–LUMO (lowest-unoccupied MO) one-electron energies difference. In both cases, $n = 8$ (there are 8 valence electrons per primitive cell), 8 electrons occupy 4 valence energy bands (for MgO crystal, the whole valence band is split into two subbands).

On the basis of Bloch functions, the Fock and overlap matrices F and S become

$$F_{\mu\nu}(\mathbf{k}) = \sum_{\mathbf{R}_n} \exp(i\mathbf{k} \mathbf{R}_n) F_{\mu\nu}(\mathbf{R}_n); \quad S_{\mu\nu}(\mathbf{k}) = \sum_{\mathbf{R}_n} \exp(i\mathbf{k} \mathbf{R}_n) S_{\mu\nu}(\mathbf{R}_n) \tag{4.56}$$

where $F_{\mu\nu}(\mathbf{R}_n)$ is the matrix element of the Fock operator between the μ th AO located in the reference (zero) cell and the ν -th AO located in the $\mathbf{R}_n$ cell. The matrix element $S_{\mu\nu}(\mathbf{R}_n)$ is the overlap integral of the same AOs. The row index can

be limited to the reference cell for translational symmetry. Matrices represented on the Bloch basis (or in $\mathbf{k}$ -space) take a block-diagonal form, as Bloch functions are bases for irreducible representations of the translation group T ($T^{(N)}$ for the cyclic cluster of N primitive cells); each block has the dimensions of the AO basis in the primitive cell, M :

$$F(\mathbf{k})C(\mathbf{k}) = S(\mathbf{k})C(\mathbf{k})E(\mathbf{k}) \quad (4.57)$$

In the HF LCAO method, (4.57) for the periodic systems replaces (4.33) written for the molecular systems. In principle, the above equation should be solved at each SCF procedure step for all the (infinite) $\mathbf{k}$ -points of the Brillouin zone. Usually, a finite set $\{\mathbf{k}_j\}$ ($j = 1, 2, \dots, L$) of $\mathbf{k}$ -points is taken (this means replacing the infinite crystal by the cyclic cluster of L primitive cells). The convergence of the results relative to the increase of the $\mathbf{k}$ -points set is examined in real calculations; for the convergent results, the interpolation techniques are used for eigenvalues and eigenvectors as these are both continuous functions of $\mathbf{k}$ [79]. The convergence of the SCF calculation results is connected with the density matrix properties considered in Sect. 4.3. The overlap matrix elements in the AO basis are the lattice sums of the overlap integrals between AOs, numbered now by indices of AO in the zero cell and of the cell defined by the translation vector $\mathbf{R}_n$:

$$S_{\mu\nu}(\mathbf{R}_n) = \int \chi_\mu^*(\mathbf{r}) \chi_\nu(\mathbf{r} - \mathbf{R}_n) d^3\mathbf{r} \quad (4.58)$$

The Fock matrix elements (as in the case of molecules) are the sums of one-electron (the kinetic energy T and the nuclear attraction energy Z) and two-electron (Coulomb J and exchange energies) parts. The difference of these matrices from the molecular analogs is the appearance of the sums over a direct lattice, containing one-electron (kinetic energy and nuclear attraction) and two-electron integrals:

$$F_{\mu\nu}(\mathbf{R}_n) = T_{\mu\nu}(\mathbf{R}_n) + Z_{\mu\nu}(\mathbf{R}_n) + J_{\mu\nu}(\mathbf{R}_n) + X_{\mu\nu}(\mathbf{R}_n) \quad (4.59)$$

$$T_{\mu\nu}(\mathbf{R}_n) = -\frac{1}{2} \int \chi_\mu^*(\mathbf{r}) \nabla_{\mathbf{r}}^2 \chi_\nu(\mathbf{r} - \mathbf{R}_n) d^3\mathbf{r} \quad (4.60)$$

$$Z_{\mu\nu}(\mathbf{R}_n) = \sum_{A=1}^{N_A} \sum_{\mathbf{R}_m} \int \chi_\mu^*(\mathbf{r}) \frac{Z_A}{|\mathbf{r} - \mathbf{A} - \mathbf{R}_m|} \chi_\nu(\mathbf{r} - \mathbf{R}_n) d^3\mathbf{r} \quad (4.61)$$

(A numbers atoms in the primitive cell)

$$J_{\mu\nu}(\mathbf{R}_n) = \sum_{\lambda\sigma} \sum_{\mathbf{R}_{m'}}^M P_{\lambda\sigma}(\mathbf{R}_{m'}) \sum_{\mathbf{R}_m} (\mu 0 \nu \mathbf{R}_n | \lambda \mathbf{R}_m \sigma (\mathbf{R}_m + \mathbf{R}_{m'})) \quad (4.62)$$

$$X_{\mu\nu}(\mathbf{R}_n) = -\frac{1}{2} \sum_{\lambda\sigma} \sum_{\mathbf{R}_{m'}}^M P_{\lambda\sigma}(\mathbf{R}_{m'}) \sum_{\mathbf{R}_m} (\mu 0 \lambda \mathbf{R}_m | \nu \mathbf{R}_n \sigma (\mathbf{R}_m + \mathbf{R}_{m'})) \quad (4.63)$$

The two-electron integrals in (4.62) and (4.63) are defined as

$$(\mu 0 \nu \mathbf{R}_n | \lambda \mathbf{R}_m \sigma (\mathbf{R}_m + \mathbf{R}_{m'})) = \int \int \chi_\mu^*(\mathbf{r}) \chi_\nu(\mathbf{r} - \mathbf{R}_n) |\mathbf{r} - \mathbf{r}'|^{-1} \chi_\lambda^*(\mathbf{r}' - \mathbf{R}_m) \chi_\sigma(\mathbf{r} - \mathbf{R}_m - \mathbf{R}_{m'}) d^3 \mathbf{r} d^3 \mathbf{r}' \quad (4.64)$$

The comparison of (4.36) and (4.64) shows the difference in the two-electron integrals definitions for crystals and molecules.

The spinless one-electron density-matrix (DM) elements are defined in the LCAO approximation as

$$P_{\lambda\sigma}(\mathbf{R}_{m'}) = 2 \int d\mathbf{k} e^{i\mathbf{k}\mathbf{R}_{m'}} \sum_i C_{i\lambda}^*(\mathbf{k}) C_{i\sigma}(\mathbf{k}) \theta(\epsilon_F - \epsilon_i(\mathbf{k})) \quad (4.65)$$

where ϵ_F is the Fermi energy and the integration in (4.65) extends to the first Brillouin zone and corresponds to the model of the infinite crystal. In the cyclic-cluster model, the integration is replaced by the summation over $\mathbf{k}$ -points numbering the irreps of the group of the inner cyclic-cluster translations. The DM elements depend on the eigenvectors $C_i(\mathbf{k})$ of the $F(\mathbf{k})$ matrix. The integration or summation over $\mathbf{k}$ in DM elements makes it impossible to solve (4.57) for different $\mathbf{k}$ independently. The electron energy of the crystal (per primitive unit cell) as calculated within the HF LCAO approximation can be expressed in terms of the one-electron density matrix (DM) and includes the lattice sums

$$E_e = \frac{1}{2} \sum_{\mu\nu} \sum_{\mathbf{R}_n}^M P_{\mu\nu}(\mathbf{R}_n) (F_{\mu\nu}(\mathbf{R}_n) + T_{\mu\nu}(\mathbf{R}_n) + Z_{\mu\nu}(\mathbf{R}_n)) \quad (4.66)$$

The direct lattice summations in the Fock matrix elements and the $\mathbf{k}$ dependence of the one-electron DM, energy levels, and COs are the main difficulties of the HF LCAO method for periodic systems, compared with molecules. A special strategy must be specified for the treatment of the infinite Coulomb and exchange series as well as for the substitution of the integral that appears in DM with a weighted sum extended to a finite set of $\mathbf{k}$ -points. The efficient solution of these problems has been implemented in the CRYSTAL code [21]. These problems are also valid for UHF and ROHF LCAO methods for periodic systems considered in the next subsection.

4.1.6 Unrestricted and Restricted Open-Shell Hartree–Fock Methods for Crystals

The unrestricted and restricted open-shell Hartree–Fock Methods (UHF and ROHF) for crystals use a single-determinant wavefunction of type (4.40) introduced for molecules. The differences appearing are common with those examined for the RHF LCAO method: use of Bloch functions for crystalline orbitals, the dependence

of the Fock matrix elements on the lattice sums over the direct lattice, and the Brillouin-zone summation in the density-matrix calculation. The use of one-determinant approaches is the only possibility of the first-principles wavefunction-based calculations for crystals as the many-determinant wavefunction approach (used for molecules) is practically unrealizable for the periodic systems. The UHF LCAO method allowed calculation of the bulk properties of different transition-metal compounds (oxides, perovskites)—the systems with open shells due to the transition-metal atom. We discuss the results of these calculations in Chap. 9. The point defects in crystals in many cases form the open-shell systems and also are interesting objects for UHF LCAO calculations (see Chap. 10).

In the UHF or ROHF cases, two sets of matrix equations are solved self-consistently for α and β spins [66]:

$$F^\alpha(\mathbf{k})C^\alpha(\mathbf{k}) = S(\mathbf{k})C^\alpha(\mathbf{k})E^\alpha(\mathbf{k}) \quad (4.67)$$

$$F^\beta(\mathbf{k})C^\beta(\mathbf{k}) = S(\mathbf{k})C^\beta(\mathbf{k})E^\beta(\mathbf{k}) \quad (4.68)$$

where the $F^\alpha(\mathbf{k})$, $F^\beta(\mathbf{k})$, and $S(\mathbf{k})$ matrices are obtained by Fourier transform from the corresponding direct-space equivalent quantities as in (4.56).

The Fourier components of the density matrix for α and β spins are different as they are obtained by using the $C^\alpha(\mathbf{k})$ and $C^\beta(\mathbf{k})$ eigenvectors obtained from (4.67) and (4.68), respectively:

$$P_{\lambda\sigma}^\alpha(\mathbf{R}_m) = \int d\mathbf{k} e^{i\mathbf{k}\cdot\mathbf{R}_m} \sum_i n_i^\alpha C_{i\lambda}^{*\alpha}(\mathbf{k}) C_{i\sigma}^\alpha(\mathbf{k}) \quad (4.69)$$

$$P_{\lambda\sigma}^\beta(\mathbf{R}_m) = \int d\mathbf{k} e^{i\mathbf{k}\cdot\mathbf{R}_m} \sum_i n_i^\beta C_{i\lambda}^{*\beta}(\mathbf{k}) C_{i\sigma}^\beta(\mathbf{k}) \quad (4.70)$$

where $n_i^{\alpha,\beta}$ are the occupations of CO by electrons with α and β spins.

The total density $P(\mathbf{R}_m)$ and spin density $P^{\text{spin}}(\mathbf{R}_m)$ Fourier components are defined as

$$P(\mathbf{R}_m) = P^\alpha(\mathbf{R}_m) + P^\beta(\mathbf{R}_m) \quad (4.71)$$

$$P^{\text{spin}}(\mathbf{R}_m) = P^\alpha(\mathbf{R}_m) - P^\beta(\mathbf{R}_m) \quad (4.72)$$

The $F^\alpha(\mathbf{R}_m)$ and $F^\beta(\mathbf{R}_m)$ matrices are defined as follows:

$$F_{\mu\nu}^\alpha(\mathbf{R}_m) = F_{\mu\nu}(\mathbf{R}_m) + X_{\mu\nu}^{\text{spin}}(\mathbf{R}_m) \quad (4.73)$$

$$F_{\mu\nu}^\beta(\mathbf{R}_m) = F_{\mu\nu}(\mathbf{R}_m) - X_{\mu\nu}^{\text{spin}}(\mathbf{R}_m) \quad (4.74)$$

The $F(\mathbf{R}_m)$ matrix is defined as in (4.59), where the total density matrix $P(\mathbf{R}_m)$ defined in (4.71) is used in the Coulomb and exchange terms; $X_{\mu\nu}^{\text{spin}}(\mathbf{R}_m)$ is defined as $X_{\mu\nu}(\mathbf{R}_m)$ in (4.63), where, however, the spin density matrix $P^{\text{spin}}(\mathbf{R}_m)$ is used instead of the total density matrix $P(\mathbf{R}_m)$.

The ROHF LCAO method for crystals differs from the UHF method in the equations defining the CO. Let $n = n_\alpha + n_\beta$ electrons per primitive unit cell be considered ($n_\alpha > n_\beta$). For the n_β CO, the closed-shell RHF LCAO equations are solved, and the CO of $n_\alpha + n_\beta$ electrons with α spin are found from the equation analogous to (4.57). In the ROHF method, the total density $P(\mathbf{R}_m)$ and spin density $P^{\text{spin}}(\mathbf{R}_m)$ matrices are defined as

$$P(\mathbf{R}_m) = P^{\alpha,\beta}(\mathbf{R}_m) + P^\alpha(\mathbf{R}_m) \quad (4.75)$$

$$P^{\text{spin}}(\mathbf{R}_m) = P^{(\alpha-\beta)}(\mathbf{R}_m) \quad (4.76)$$

In (4.75), $P^{\alpha,\beta}$ is the DM calculated with the doubly occupied COs, and in (4.76), $P^{(\alpha-\beta)}$ is DM calculated for COs with α spin.

The UHF method many-electron wavefunction is the eigenfunction of the spin-projection operator $\hat{S}_z$ with zero eigenvalue, and the ROHF method many-electron function describes the spin state with the maximally possible spin projection $S_z = \frac{1}{2}(n_\alpha - n_\beta)$. If we compare the UHF scheme with the RHF scheme for the closed-shell case, we see that the most relevant quantities (Fock and density matrices, eigenvalues and eigenvectors) are duplicated, so that it is possible to differentiate α orbitals from β orbitals. As in the case of molecules, it is important that at the starting guess, P^α and P^β density matrices are different. In the CRYSTAL code, there exists an option to construct a DM formed by the superposition of atomic solutions, where it is possible to assign a specific polarization (or no polarization) to each atom of the system [66]. Once the SCF process is started, it is often useful to introduce some constraints on the populations of the α and β orbitals. This is performed in the CRYSTAL code by *ad hoc* translations of the eigenvalues spectrum in such a way that the difference between the number of α and β electrons is equal to the value introduced in the input.

It is well known from Hartree–Fock studies of molecular systems that it is very common to have problems of SCF convergence when studying open-shell systems; similarly, convergence problems are not rare in the Hartree–Fock treatment of spin-polarized crystals. A well-known technique for the solution of convergence problems, in the case of open-shell molecules, is the so-called level-shifting method [80]; this approach has shown its effectiveness in the periodic HF context also, especially in the case of crystals containing transition elements.

4.2 Special Points of Brillouin Zone

4.2.1 Supercells of Three-Dimensional Bravais Lattices

Let $\mathbf{a}_i(\Gamma_1)$ ($i = 1, 2, 3$) be the basic translation vectors of the initial direct lattice of type Γ_1 and $\mathbf{a}_j(\Gamma_2)$ ($j = 1, 2, 3$) be the basic translation vectors of a new lattice of type Γ_2 with the same point symmetry (symmetrical transformation) but composed of supercells. Then

$$\mathbf{a}_j(\Gamma_2) = \sum_i l_{ji}(\Gamma_2\Gamma_1) \mathbf{a}_i(\Gamma_1) \quad |\det l| = L, j = 1, 2, 3 \quad (4.77)$$

where $l_{ji}(\Gamma_2\Gamma_1)$ are integer elements of the matrix $l(\Gamma_2\Gamma_1)$ defining the transition from the lattice of type Γ_1 to the lattice of type Γ_2 .

The vectors $\mathbf{a}_j(\Gamma_2)$ have well-defined orientation with respect to point-symmetry elements of the lattices that are the same for both lattices because of the symmetrical character of the transformation (4.77). Let us define the components of the vectors $\mathbf{a}_j(\Gamma_2)$ by the parameters s_k assuring their correct orientation relative to the lattice symmetry elements and the correct relations between their lengths (if there are any). Then three vector relations (4.77) give nine linear nonhomogeneous equations to determine nine matrix elements $l_{ij}(\Gamma_2\Gamma_1)$ as functions of the parameters s_k . The requirements that these matrix elements must be integers define the possible values of the parameters s_k giving the solution of the problem.

Let us demonstrate the procedure of finding the matrix of a symmetrical transformation (4.77) by the example of the rhombohedral crystal system where there is only one lattice type (R). The basic translation vectors of the initial lattice are the following:

$$\mathbf{a}_1 = (a, 0, c) \quad \mathbf{a}_{2,3} = (-a/2, \pm a\sqrt{3}/2, c)$$

The basic translation vectors of the new lattice composed of supercells for symmetrical transformation (4.77) have the same form (the parameters a and c of the initial lattice are replaced with the parameters s_1a, s_2c):

$$\mathbf{a}_1 = (s_1a, 0, s_2c) \quad \mathbf{a}_{2,3} = (-s_1a/2, \pm s_1a\sqrt{3}/2, s_2c)$$

Inserting them in (4.77), one obtains nine equations for nine elements of the matrix l . The solution of this system is

$$l_{ij} = \frac{s_2 + 2s_1}{3} \delta_{ij} + \frac{s_2 - s_1}{3} (1 - \delta_{ij})$$

where $i, j = 1, 2, 3$. As the matrix elements l_{ij} must be integers, let us assign $(s_2 - s_1)/3 = n_2$ and $(s_2 + 2s_1)/3 = n_1 + n_2$. The matrix of the symmetrical transformation for a rhombohedral lattice with the corresponding value of L may be found in Appendix A and [81] where the matrices of the symmetrical transformations for all three-dimensional crystal lattices are given. Let us explain the peculiarities of the consideration made for each of the seven possible crystal systems.

In the triclinic crystal system, an arbitrary matrix with integer elements defines a symmetrical transformation (any transformation seems to be symmetrical because of the low point symmetry of the lattice).

In the monoclinic crystal system, there are two lattices: simple (P) and base-centered (A), each of which is defined by five parameters. Therefore, the matrices of symmetrical transformations are determined by five integers.

In the hexagonal crystal system, there is only one lattice type (P), but the basic translation vectors may be oriented in two different ways relative to the basic translation vectors of the initial lattice: either parallel to them or rotated through an angle of $\pi/6$ about the z -axis. Therefore, two types of symmetrical transformation are possible in this case (with two parameters for each).

In the orthorhombic crystal system, the base-centered lattice merits special attention because of different possible settings. Let the initial base-centered lattice have the setting C . The transition to base-centered lattices with settings C and A (or B) gives different results (see Appendix A). The change of setting for the transition to other types of lattice does not give new supercells.

In the tetragonal crystal system, there are two types of Bravais lattice (P and I). All their symmetrical transformations may be obtained from the symmetrical transformations for orthorhombic lattices if one sets $n_1 = n_2$ and takes into account that base-centered and face-centered orthorhombic lattices become simple and body-centered tetragonal ones, respectively.

The matrices of symmetrical transformations for all the types (P, F, I) of cubic lattices may also be obtained from the matrices of symmetrical transformations for orthorhombic lattices if one sets $n_1 = n_2 = n_3 = n$.

4.2.2 Special Points of Brillouin-Zone Generating

In self-consistent calculations of the electronic structure of crystals both in the basis of plane waves and in the basis of localized atomic-type functions, one needs in every stage of the self-consistent procedure to evaluate an approximate electron-density matrix by integration over the Brillouin zone (BZ):

$$\rho(\mathbf{r}, \mathbf{r}') = \int_{\text{BZ}} Q_{\mathbf{r}, \mathbf{r}'}(\mathbf{k}) d\mathbf{k}, \quad Q_{\mathbf{r}, \mathbf{r}'}(\mathbf{k}) = \sum_v \psi_v^*(\mathbf{k}, \mathbf{r}') \psi_v(\mathbf{k}, \mathbf{r}) \quad (4.78)$$

where the sum is over occupied electronic states of the crystal. In practice, $\psi(\mathbf{k}, \mathbf{r})$ (and $\varphi(\mathbf{k}) \equiv Q_{\mathbf{r}, \mathbf{r}'}(\mathbf{k})$) are calculated in some finite meshes of $\mathbf{k}$ -points. Therefore, one needs for the evaluation of the integral (4.78) to construct the interpolation formula of the numerical integration based on an interpolation procedure by means of some set of interpolation functions.

The functions $\varphi(\mathbf{k}) \equiv Q_{\mathbf{r}, \mathbf{r}'}(\mathbf{k})$ are periodic in the reciprocal space with periods determined by the basic translation vectors $\mathbf{b}_i$ of the reciprocal lattice and having the full point symmetry of the crystal (F is a point group of order n_F of the crystal).

$$\varphi(\mathbf{k} + \mathbf{b}_m) = \varphi(\mathbf{k}) = \varphi(f\mathbf{k}), \quad f \in F, \quad \mathbf{b}_m = \sum_{i=1}^3 m_i \mathbf{b}_i \quad (4.79)$$

The plane waves $\exp(i\mathbf{k} \cdot \mathbf{a}_n)$ seem to be the most convenient as interpolation functions for the integrand in the BZ integration, where $\mathbf{a}_n = \sum_{i=1}^3 n_i \mathbf{a}_i$ are direct lattice translation vectors and $\mathbf{a}_i$ are primitive translations. It is easy with plane waves to take into account the translational and point symmetry of the crystal.

In the problem of BZ integration, nodes for the interpolation ($\mathbf{k}$ -points of the BZ) were called special points (SP).

Many procedures for special-points generation have been proposed [82–85]. The supercell (large unit cell–small Brillouin zone) method appears to be the most general and fruitful in practical applications [81, 82] as it gives as a rule the most efficient sets of special points.

Let $\mathbf{B}_i(\Gamma_1)$ ($i = 1, 2, 3$) and $\mathbf{b}_j(\tilde{\Gamma}_2)$ ($j = 1, 2, 3$) be basic translation vectors of the reciprocal lattices corresponding to direct ones determined by basic translation vectors $\mathbf{a}_i(\Gamma_1)$ and $\mathbf{a}_j(\Gamma_2)$, respectively. The transformation (4.77) of the direct lattices is accompanied by the following transformation of reciprocal lattices:

$$\mathbf{b}_j(\tilde{\Gamma}_2) = \sum_i (l^{-1}(\Gamma_2\Gamma_1))_{ij} \mathbf{B}_i(\tilde{\Gamma}_1) \quad (4.80)$$

For the symmetrical transformation (4.77), the transformation (4.80) is also symmetrical as it does not change the point symmetry of the reciprocal lattice. The symmetrical transformation is compatible with the change of the reciprocal lattice type in the limits of the same crystal system too. The vectors $\mathbf{b}_j$ defining the small Brillouin zone are very important in the theory of special points [81]. Let $f(\mathbf{K})$ be the function with a point symmetry F to be integrated over the initial Brillouin zone where the wavevector $\mathbf{K}$ varies. Usually, the point-symmetry group F either coincides with the crystal class $\tilde{F}$ of the crystal (if $\tilde{F}$ contains the inversion I) or $F = \tilde{F} \times C_i$ (otherwise) [81]. The function $f(\mathbf{K})$ may be expanded in Fourier series over symmetrized plane waves $P_m(\mathbf{K})$:

$$f(\mathbf{K}) = \sum_m f_m P_m(\mathbf{K}) \quad (4.81)$$

$$P_m(\mathbf{K}) = \frac{1}{n_G} \sum_{g \in G} \exp(i\mathbf{K} \cdot g\mathbf{a}_m) \quad (4.82)$$

where $\mathbf{a}_m = \sum_{i=1}^3 m_i \mathbf{a}_i$ is some translation vector of the direct lattice and the integer $m = 0, 1, 2, \dots$ numerates the stars of vectors $g\mathbf{a}_m$ ($g \in F$) in order of increasing length. The functions $P_m(\mathbf{K})$ have the properties [83]:

$$\frac{1}{V_{\text{BZ}}} \int_{\text{BZ}} P_m(\mathbf{K}) d\mathbf{K} = \delta_{m0}, \quad m = 0, 1, 2, \dots \quad (4.83)$$

Let $\bar{m}$ be a subset of m corresponding to the stars of vectors $g\mathbf{a}_m$ ($g \in F$). As is proved in [81], for symmetrical transformation (4.77) L points in the initial Brillouin zone (related to the initial basic translation vectors $\mathbf{a}_i$),

$$\mathbf{K}_t^{(k)} = \mathbf{k} + \sum_j q_{tj} \mathbf{b}_j \quad (4.84)$$

where q_{tj} are integers and $\mathbf{k}$ is an arbitrary vector in the small Brillouin zone (related to the basic translation vectors $\mathbf{a}_j$), satisfy the relation:

$$\sum_{t=1}^L P_m(\mathbf{K}_t^{(k)}) = L \sum_{\bar{m}} P_{\bar{m}}(\mathbf{k}) \delta_{m\bar{m}} \quad (4.85)$$

or

$$\sum_{s=1}^N w_s P_m(\mathbf{K}_s^{(k)}) = \sum_{\bar{m}} P_{\bar{m}}(\mathbf{k}) \delta_{m\bar{m}} \quad (4.86)$$

In the latter relation s numbers, the different irreducible wavevector $\mathbf{K}$ stars that contain the points (4.84) and $w_s = L_s/L$ (L_s is the number of points (4.84) belonging to the s th star, $\sum_{s=1}^N L_s = L$). The points $\mathbf{K}_s^{(k)}$ are usually chosen in the irreducible part of the Brillouin zone.

Relations (4.81)–(4.83) give the following formula of the approximative numerical integration:

$$\frac{1}{V_{\text{BZ}}} \int_{\text{BZ}} f(\mathbf{K}) d\mathbf{K} \approx \sum_{s=1}^N w_s f(\mathbf{K}_s^{(k)}) \quad (4.87)$$

Let $M = s_o$ be the number denoting the set of vectors $g\mathbf{a}_m$ with the smallest (nonzero) lengths. If $f(\mathbf{K})$ is some linear combination of $P_m(\mathbf{K})$ with $m < M$, then the formula (4.87) appears to be exact. The number M characterizes the accuracy of the numerical integration formula. The special choice of $\mathbf{k}$ can either increase the accuracy M or change the number N of points $\mathbf{K}_s^{(k)}$ (or both) [84].

To generate the set of points $\mathbf{K}_s^{(k)}$ for any of the 14 Bravais lattices, it is sufficient to find the inverse of the corresponding matrix from Appendix A, to pick out according to (4.84) L points in the Brillouin zone related to basic translation vectors $\mathbf{a}_i$, and to distribute them over stars. The distribution of these points over stars depends on the symmetry group F of the function $f(\mathbf{K})$ and cannot be made in general form.

The sets of special points for numerical integration over the Brillouin zone of cubic crystals are given in Tables 4.1–4.3. They are obtained by symmetrical increasing of the unit cells of cubic lattices for $L \leq 32$. The tables contain the sets (4.84) with $\mathbf{k} = 0$ and some efficient sets with $\mathbf{k} \neq 0$. Some sets were found earlier in [82, 84]. The types of lattices (TL) composed of supercells are indicated in the second columns. The symbols of the matrices $\mathbf{Q} = l^{-1}$ of the transformation of basic vectors of reciprocal lattices are given in the third column. The matrices $\mathbf{Q}_i$ themselves are given in Appendix B.

The system of symmetrized plane waves $P_m(\mathbf{K})$ depends on the crystal class. Therefore, the number M that characterizes the efficiency of the set of special points

Table 4.1 Special points of the Brillouin zone for the simple cubic lattice generated by the symmetrical transformation; $\mathbf{B}_1 = \frac{2\pi}{a}(1, 0, 0)$, $\mathbf{B}_2 = \frac{2\pi}{a}(0, 1, 0)$, $\mathbf{B}_3 = \frac{2\pi}{a}(0, 0, 1)$; $\mathbf{K}_s = \alpha_1 \mathbf{B}_1 + \alpha_2 \mathbf{B}_2 + \alpha_3 \mathbf{B}_3 \equiv (\alpha_1, \alpha_2, \alpha_3)$

L	TL	$l^{(-1)}$	M	Special points $\mathbf{K}_s$ and weights w_s in $\{\}$			
2	F	$\frac{1}{2}Q_2$	2	$(0, 0, 0) \{\frac{1}{2}\}$	$(\frac{1}{2}, \frac{1}{2}, \frac{1}{2}) \{\frac{1}{2}\}$		
4	I	$\frac{1}{2}Q_3$	3	$(0, 0, 0) \{\frac{1}{4}\}$	$(\frac{1}{2}, \frac{1}{2}, 0) \{\frac{3}{4}\}$		
			4	$(\frac{1}{4}, 0, 0) \{\frac{1}{4}\}$	$[(\frac{1}{2}, 0, \frac{1}{4}) \{\frac{1}{4}\}]$	$(\frac{1}{2}, \frac{1}{4}, 0) \{\frac{1}{4}\}]$	$(\frac{1}{2}, \frac{1}{2}, \frac{1}{4}) \{\frac{1}{4}\}$
8	P	$\frac{1}{2}Q_1$	4	$(0, 0, 0) \{\frac{3}{8}\}$	$(\frac{1}{2}, 0, 0) \{\frac{3}{8}\}$	$(\frac{1}{2}, \frac{1}{2}, 0) \{\frac{3}{8}\}$	$(\frac{1}{2}, \frac{1}{2}, \frac{1}{2}) \{\frac{1}{8}\}$
			15(19)	$(\frac{1}{8}, \frac{1}{8}, \frac{1}{8}) \{\frac{1}{8}\}$	$(\frac{3}{8}, \frac{1}{8}, \frac{1}{8}) \{\frac{3}{8}\}$	$(\frac{3}{8}, \frac{3}{8}, \frac{1}{8}) \{\frac{3}{8}\}$	$(\frac{3}{8}, \frac{3}{8}, \frac{3}{8}) \{\frac{1}{8}\}$
16	F	$\frac{1}{4}Q_2$	7	$(0, 0, 0) \{\frac{1}{16}\}$	$(\frac{1}{4}, \frac{1}{4}, \frac{1}{4}) \{\frac{1}{2}\}$	$(\frac{1}{2}, 0, 0) \{\frac{3}{16}\}$	$(\frac{1}{2}, \frac{1}{2}, 0) \{\frac{3}{16}\}$
				$(1, 1, 1) \{\frac{1}{16}\}$			
27	P	$\frac{1}{3}Q_1$	9	$(0, 0, 0) \{\frac{1}{27}\}$	$(\frac{1}{3}, 0, 0) \{\frac{2}{9}\}$	$(\frac{1}{3}, \frac{1}{3}, 0) \{\frac{4}{9}\}$	$(\frac{1}{3}, \frac{1}{3}, \frac{1}{3}) \{\frac{8}{27}\}$
32	I	$\frac{1}{4}Q_3$	12	$(0, 0, 0) \{\frac{1}{32}\}$	$(\frac{1}{4}, \frac{1}{4}, 0) \{\frac{3}{8}\}$	$(\frac{1}{2}, 0, 0) \{\frac{3}{32}\}$	$(\frac{1}{2}, \frac{1}{4}, \frac{1}{4}) \{\frac{3}{8}\}$
				$(\frac{1}{2}, \frac{1}{2}, 0) \{\frac{3}{32}\}$	$(\frac{1}{2}, \frac{1}{2}, \frac{1}{2}) \{\frac{1}{32}\}$		

Table 4.2 Special points of the Brillouin zone for the face-centered cubic lattice^a generated by the symmetrical transformation

L	TL	$l^{(-1)}$	M	Special points $\mathbf{K}_s$ and weights w_s in $\{\}$			
4	P	$\frac{1}{2}Q_3$	2	$(0, 0, 0) \{\frac{1}{4}\}$	$(0, \frac{1}{2}, \frac{1}{2}) \{\frac{3}{4}\}$		
			2	$(\frac{1}{4}, \frac{1}{4}, \frac{1}{2}) \{1\}$			
			2	$(\frac{1}{2}, \frac{1}{2}, \frac{1}{2}) \{1\}$			
8	F	$\frac{1}{2}Q_1$	4	$(0, 0, 0) \{\frac{1}{8}\}$	$(\frac{1}{2}, \frac{1}{2}, \frac{1}{2}) \{\frac{1}{2}\}$	$(0, \frac{1}{2}, \frac{1}{2}) \{\frac{3}{8}\}$	
			4	$(0, \frac{1}{4}, \frac{1}{4}) \{\frac{1}{4}\}$	$(\frac{1}{4}, \frac{1}{4}, \frac{1}{2}) \{\frac{1}{2}\}$	$(\frac{1}{4}, \frac{1}{4}, \frac{1}{2}) \{\frac{1}{4}\}$	
			8(10)	$(\frac{1}{4}, \frac{1}{4}, \frac{1}{4}) \{\frac{1}{4}\}$	$(\frac{1}{2}, \frac{1}{2}, \frac{1}{4}) \{\frac{3}{4}\}$		
16	I	$\frac{1}{4}Q_4$	6(7)	$(0, 0, 0) \{\frac{1}{16}\}$	$(\frac{1}{4}, \frac{1}{4}, \frac{1}{2}) \{\frac{3}{4}\}$	$(0, \frac{1}{2}, \frac{1}{2}) \{\frac{3}{16}\}$	
			6(7)	$(0, \frac{1}{4}, \frac{1}{4}) \{\frac{3}{8}\}$	$(\frac{1}{2}, \frac{1}{2}, \frac{1}{2}) \{\frac{1}{4}\}$	$(\frac{1}{4}, \frac{1}{4}, \frac{1}{2}) \{\frac{3}{8}\}$	
27	F	$\frac{1}{3}Q_1$	9	$(0, 0, 0) \{\frac{1}{27}\}$	$(\frac{1}{3}, \frac{1}{3}, \frac{1}{3}) \{\frac{8}{27}\}$	$(0, \frac{1}{3}, \frac{1}{3}) \{\frac{2}{9}\}$	$(\frac{1}{3}, \frac{1}{3}, \frac{2}{3}) \{\frac{4}{9}\}$
32	P	$\frac{1}{4}Q_3$	8	$(0, 0, 0) \{\frac{1}{32}\}$	$(0, \frac{1}{4}, \frac{1}{4}) \{\frac{3}{16}\}$	$(\frac{1}{4}, \frac{1}{4}, \frac{1}{2}) \{\frac{3}{8}\}$	$(\frac{1}{2}, \frac{1}{2}, \frac{1}{2}) \{\frac{1}{8}\}$
				$(0, \frac{1}{2}, \frac{1}{2}) \{\frac{3}{32}\}$	$(\frac{1}{4}, \frac{1}{2}, \frac{3}{4}) \{\frac{3}{16}\}$		
			8	$(\frac{1}{4}, \frac{1}{4}, \frac{1}{4}) \{\frac{1}{4}\}$	$(\frac{1}{2}, \frac{1}{2}, \frac{1}{4}) \{\frac{3}{4}\}$		

^a $\mathbf{B}_1 = \frac{2\pi}{a}(-1, 1, 1)$, $\mathbf{B}_2 = \frac{2\pi}{a}(1, -1, 1)$, $\mathbf{B}_3 = \frac{2\pi}{a}(1, 1, -1)$
 $\mathbf{K}_s = \alpha_1 \mathbf{B}_1 + \alpha_2 \mathbf{B}_2 + \alpha_3 \mathbf{B}_3 \equiv (\alpha_1, \alpha_2, \alpha_3)$

may be different for different crystal classes [81]. In Tables 4.1–4.3, the numbers M are given for crystal classes T_d , O , O_h and T , T_h (in parentheses).

In addition, in Table 4.1 for $L = 4$, two special points $(1/2, 0, 1/4)$ and $(1/2, 1/4, 0)$ are related to different stars in crystal classes T , T_h , and each of them is a special point with the weight $1/4$; in crystal classes T_d , O , O_h , they are related to the same star, and this three-special-point set contains only one of these points with the weight $1/2$.

Table 4.3 Special points of the Brillouin zone for the body-centered cubic lattice^a generated by the symmetrical transformation

L	TL	$l^{(-1)}$	M	Special points K_s and weights w_s in $\{\}$			
2	P	$\frac{1}{2}Q_2$	2	$(0, 0, 0) \{\frac{1}{2}\}$	$(\frac{1}{2}, \frac{1}{2}, \frac{1}{2}) \{\frac{1}{2}\}$		
			2	$(\frac{1}{4}, \frac{1}{4}, \frac{1}{4}) \{1\}$			
			2	$(0, 0, \frac{1}{2}) \{1\}$			
			2	$(\frac{1}{4}, \frac{1}{4}, \frac{1}{4}) \{1\}$			
			3	$(\frac{1}{12}, \frac{1}{4}, \frac{1}{4}) \{1\}$			
4	F	$\frac{1}{4}Q_5$	3	$(0, 0, 0) \{\frac{1}{4}\}$	$(\frac{1}{4}, \frac{1}{4}, \frac{1}{4}) \{\frac{1}{2}\}$	$(\frac{1}{2}, \frac{1}{2}, \frac{1}{2}) \{\frac{1}{4}\}$	
			3	$(\frac{1}{4}, \frac{1}{4}, \frac{1}{4}) \{\frac{1}{2}\}$	$(0, 0, \frac{1}{2}) \{\frac{1}{2}\}$		
			6	$(\frac{1}{8}, \frac{1}{8}, \frac{1}{8}) \{\frac{1}{2}\}$	$(\frac{3}{8}, \frac{3}{8}, \frac{3}{8}) \{\frac{1}{2}\}$		
8	I	$\frac{1}{2}Q_1$	5	$(0, 0, 0) \{\frac{1}{8}\}$	$(0, 0, \frac{1}{2}) \{\frac{3}{4}\}$	$(\frac{1}{2}, \frac{1}{2}, \frac{1}{2}) \{\frac{1}{8}\}$	
			5	$(\frac{1}{4}, \frac{1}{4}, \frac{1}{4}) \{\frac{3}{4}\}$	$(\frac{1}{4}, \frac{1}{4}, \frac{1}{4}) \{\frac{1}{4}\}$		
			6	$(0, 0, \frac{1}{4}) \{\frac{1}{4}\}$	$(0, \frac{1}{4}, \frac{1}{4}) \{\frac{1}{2}\}$	$(\frac{1}{4}, \frac{1}{4}, \frac{1}{2}) \{\frac{1}{4}\}$	
16	P	$\frac{1}{4}Q_2$	6	$(0, 0, 0) \{\frac{1}{16}\}$	$(\frac{1}{4}, \frac{1}{4}, \frac{1}{4}) \{\frac{3}{8}\}$	$(0, 0, \frac{1}{2}) \{\frac{3}{8}\}$	$(\frac{1}{4}, \frac{1}{4}, \frac{1}{4}) \{\frac{1}{8}\}$
			6	$(\frac{1}{2}, \frac{1}{2}, \frac{1}{2}) \{\frac{1}{16}\}$			
27	I	$\frac{1}{3}Q_1$	10(11)	$(\frac{1}{8}, \frac{1}{8}, \frac{1}{8}) \{\frac{1}{8}\}$	$(\frac{1}{8}, \frac{1}{8}, \frac{3}{8}) \{\frac{1}{2}\}$	$(\frac{5}{8}, \frac{3}{8}, \frac{3}{8}) \{\frac{1}{8}\}$	$(\frac{3}{8}, \frac{1}{8}, \frac{1}{8}) \{\frac{1}{4}\}$
			10(11)	$(0, 0, 0) \{\frac{1}{27}\}$	$(0, 0, \frac{1}{3}) \{\frac{4}{9}\}$	$(\frac{1}{3}, \frac{1}{3}, \frac{1}{3}) \{\frac{2}{9}\}$	$(0, \frac{1}{3}, \frac{1}{3}) \{\frac{8}{27}\}$
32	F	$\frac{1}{8}Q_5$	12	$(0, 0, 0) \{\frac{1}{32}\}$	$(\frac{1}{8}, \frac{1}{8}, \frac{1}{8}) \{\frac{1}{4}\}$	$(\frac{1}{4}, \frac{1}{4}, \frac{1}{4}) \{\frac{3}{16}\}$	$(0, 0, \frac{1}{2}) \{\frac{3}{16}\}$
			12	$(\frac{1}{8}, \frac{3}{8}, \frac{3}{8}) \{\frac{1}{4}\}$	$(\frac{1}{4}, \frac{1}{4}, \frac{1}{4}) \{\frac{1}{16}\}$	$(\frac{1}{2}, \frac{1}{2}, \frac{1}{2}) \{\frac{3}{32}\}$	

^a $B_1 = \frac{2\pi}{a}(0, 1, 1)$, $B_2 = \frac{2\pi}{a}(1, 0, 1)$, $B_3 = \frac{2\pi}{a}(1, 1, 0)$

$$K_s = \alpha_1 B_1 + \alpha_2 B_2 + \alpha_3 B_3 \equiv (\alpha_1, \alpha_2, \alpha_3)$$

4.2.3 Modification of the Monkhorst–Pack Special-Points Meshes

The most popular special-points (SP) sets are meshes obtained by a very simple algorithm proposed by Monkhorst and Pack (MP) in [85]:

$$\mathbf{k}_p^{(n)} = \sum_{i=1}^3 u_{p_i}^{(n)} \mathbf{b}_i, n = 1, 2, \dots, p_i = 1, 2, \dots, n, \quad u_{p_i}^{(n)} = \frac{2p_i - n - 1}{2n} \quad (4.88)$$

These meshes are widespread in modern Hartree–Fock and density-functional theory calculations of crystals and are automatically generated in the corresponding computer codes. But MP meshes of SP have at least one shortcoming, which may be understood if one oversees the problem from the point of view of the more general large unit cell–small Brillouin zone (LUC–SBZ) method of SP generation. The MP method is a particular case of the LUC–SBZ method. In [86], the modification of

Table 4.4 Characteristics of MP, MMP1, and MMP2 $\mathbf{k}$ -points meshes for sc and bcc cubic lattices (R_{cut} and M are the cutoff length and the precision of the meshes, N is the number of $\mathbf{k}$ -points in the IBZ, R_{cut} is in a units, a is a cubic lattice constant)

$4R_{\text{cut}}^2$ (in a^2), M , N															
sc								bcc							
n	$\Gamma\text{M}=\text{MP}$			$\text{MMP1}=\text{MMP2}$				$\Gamma\text{M}=\text{MP}$			MMP1		MMP2		
1	4	1	1	16	4	1		3	1	1	4	2	1	8	3
2	16	4	4	64	15	4		12	5	3	16	6	2	32	12
3	36	9	4	144	40	10		27	10	4	36	14	5	72	30
4	64	15	10	256	79	20		48	19	8	64	26	8	128	59
5	100	25	10	400	141	35		75	32	10	100	45	14	200	104
6	144	40	20	576	224	56		108	51	16	144	70	20	288	163
7	196	56	20	784	341	84		147	72	20	196	102	30	392	221
8	256	79	35	1024	488	120		192	99	29	256	143	40	512	265

the MP meshes was suggested that makes faster and more regular convergence of the results of the self-consistent calculations of the electronic structure of crystals.

MP meshes (4.88) are a particular case of the meshes (4.84), which corresponds to the transformation (4.77) with the diagonal matrices

$$l_{ji}^{(n)} = n\delta_{ji}, \quad L = n^3, \quad n = 1, 2, \dots, \quad i, j = 1, 2, 3 \quad (4.89)$$

and a special choice of $\mathbf{k}$ in (4.84):

$$\mathbf{k} = \begin{cases} \frac{1}{2n}(\mathbf{b}_1 + \mathbf{b}_2 + \mathbf{b}_3) \\ 0 \end{cases} = \begin{cases} \left(\frac{1}{2n}(1, 1, 1) \right) & \text{for even } n \\ 0 & \text{for odd } n \end{cases} \quad (4.90)$$

The $\mathbf{k}$ -vector choice (4.90) is not the best one. As an example, we demonstrate this for cubic crystals. In this case, transformation (4.89) assures at least the cutoff length $R_{\text{cut}} = n \cdot |\mathbf{a}_i|$ whatever the $\mathbf{k}$. The $\mathbf{k}$ -vector choice (4.90) increases slightly the cutoff length R_{cut} for even n in an fcc lattice (see Table 4.4).

In all the other cases of cubic crystals (in bcc and sc lattices and for odd n in fcc lattice), the meshes MP (4.88) do not increase the standard cutoff length $R_{\text{cut}} = n \cdot |\mathbf{a}_i|$ and are equivalent to the meshes with $\mathbf{k} = 0$ that contain the point Γ and consist of the whole $\mathbf{k}$ -stars.

In [86], another choice of the $\mathbf{k}$ -point in (4.88) was proposed, and the corresponding SP sets were called modified MP (MMP) meshes. They depend on the type of cubic crystal lattice.

1. $\tilde{\mathbf{k}} = \frac{1}{4n}(1, 1, 1)$ for sc lattice (MMP1=MMP2).
2. $\tilde{\mathbf{k}} = \frac{1}{4n}(1, 1, 1)$ (MMP1) and $\tilde{\mathbf{k}} = \frac{1}{4n}(-1/3, 1, 1)$ (MMP2) for bcc lattice.
3. $\tilde{\mathbf{k}} = \frac{1}{2n}(1, 1, 1)$ (MMP1) and $\tilde{\mathbf{k}} = \frac{1}{2n}(0.4588, 0.3112, 0.1477)$ (MMP2) for fcc lattice.

Table 4.5 Characteristics of Γ M, MP, MMP1, and MMP2 $\mathbf{k}$ -points meshes for fcc cubic lattice and convergence of PW DFT binding energy E per unit cell (in eV) for SiC crystal for Γ M, MP, and MMP2 $\mathbf{k}$ -points meshes [86] (R_{cut} and M are the cutoff length and the precision of the meshes, N is the number of $\mathbf{k}$ -points in the IBZ, R_{cut} is in a units, a is a cubic lattice constant)

Γ M					MP				MMP1				MMP2		
n	$4R_{\text{cut}}^2$	M	N	E	$4R_{\text{cut}}^2$	M	N	E	$4R_{\text{cut}}^2$	M	N	E	$4R_{\text{cut}}^2$	M	N
1	2	1	1	-2.931	2	1	1	-2.931	4	2	1	12.843	6	3	1
2	8	4	3	12.236	16	8	2	14.990	16	8	2	14.990	24	13	6
3	18	9	4	14.615	18	9	4	14.615	36	20	6	15.100	54	33	18
4	32	17	8	14.987	64	40	10	15.110	64	40	10	15.110	96	67	40
5	50	29	10	15.076	50	29	10	15.076	100	71	19	15.111	150	121	75
6	72	47	16	15.100	144	113	28	15.111	144	113	28	15.111	216	180	126
7	98	68	20	15.108	98	68	20	15.108	196	163	44	15.111	294	227	196
8	128	98	29	15.110	256	207	60	15.111	256	207	60	15.111	384	253	288

The main characteristics of the proposed meshes for sc and bcc lattices are given in Table 4.4 and for fcc lattice in Table 4.5.

MMP2 meshes are the best ones as they give the maximal value of the cutoff length R_{cut} and the precision M for the given transformation (4.89). MMP1 meshes for bcc and fcc lattices give the smaller value of the cutoff length and the precision but, at the same time, consist of the smaller number of points in the IBZ. The one-SP meshes MMP2 (for $n = 1$) are mean value points of Baldereschi [87].

The idea of the proposed modification of the MP meshes can be also used to generate MMP meshes for all noncubic lattices.

The efficiency of MMP $\mathbf{k}$ -points meshes is demonstrated for an fcc lattice in Table 4.5, where PW DFT binding energies E per unit cell (in eV) for SiC crystal (fcc lattice) are given for different choices of $\mathbf{k}$ -meshes.

DFT-PW calculations [86] were performed on a SiC crystal for different SP meshes to investigate which one corresponds to the best convergence of the results for the total energy per unit cell. The experimental value $a = 4.35 \text{ \AA}$ was taken for the fcc lattice constant of SiC, the electron-ion interaction was described by ultrasoft, Vanderbilt-type pseudopotentials [88], and the cutoff energy for the plane-wave basis set was taken to be 1,000 eV. The generalized gradient corrections (GGA) DFT method was used (see Chap. 7). In Table 4.5, the calculated binding energy values (defined as the difference between the sum of Si and C atomic energies with Vanderbilt-type pseudopotentials and the total energy per primitive unit cell) are given for three types of meshes mentioned above and used in calculations. As is seen, the faster convergence takes place for the modified Monkhorst-Pack schemes. For comparison, the experimental 13.0 eV and Hartree-Fock 9.0 eV may be found in [89].

The suggested modification of Monkhorst-Pack special-points meshes for Brillouin-zone integration is essentially useful for crystals with many atoms in a primitive unit cell or for point defect calculations in a supercell model.

In these cases, each step of the self-consistent procedure in Hartree–Fock or DFT calculations is time consuming, so that the higher efficiency of $\mathbf{k}$ -point meshes shortens the computing time. It is also important for the lattice parameters or atom-position optimization in crystals, when the self-consistent procedure is repeated for different atomic structures. The special-point set generation considered can be applied both in LCAO and plane-wave calculations to approximate the DM of a crystal.

4.3 Density Matrix of Crystals in the Hartree–Fock Method

4.3.1 Properties of the One-Electron Density Matrix of a Crystal

As is well known, the energy of a system within the single-determinant Hartree–Fock approximation can be expressed in terms of the one-electron density matrix (DM). The one-electron spinless DM $\rho(\mathbf{R}, \mathbf{R}')$ is defined as

$$\rho(\mathbf{R}, \mathbf{R}') = \int_{V_N} \psi(\mathbf{R}, \mathbf{R}_2, \dots, \mathbf{R}_M) \psi^*(\mathbf{R}', \mathbf{R}_2, \dots, \mathbf{R}_M) d^3\mathbf{R}_2, d^3\mathbf{R}_3 \dots d^3\mathbf{R}_M \quad (4.91)$$

where the electron position vectors $\mathbf{R}$ and $\mathbf{R}'$ vary within the basic domain of a crystal of volume V_N , that is, a cyclic cluster consisting of N primitive unit cells. The DM of the infinite crystal is obtained from the DM of the basic domain by taking the limit $N \rightarrow \infty$. In its translational symmetry, the DM is periodic on the direct lattice:

$$\rho(\mathbf{R}, \mathbf{R}') = \rho(\mathbf{R} + \mathbf{R}_n, \mathbf{R}' + \mathbf{R}_n) \quad (4.92)$$

where $\mathbf{R}_n$ is an arbitrary translation vector of the Bravais lattice.

We will represent the electron position vector $\mathbf{R}$ in the form $(\mathbf{r}, \mathbf{R}_n)$, where $\mathbf{R}_n$ specifies the primitive cell within which the end of the vector $\mathbf{R}$ lies and $\mathbf{r}$ is the position vector of an electron within this primitive cell. Therefore, we have $\mathbf{R} = \mathbf{r} + \mathbf{R}_n$. Using (4.92), the density matrix can be written in the form

$$\rho(\mathbf{R}, \mathbf{R}') = \rho(\mathbf{r} + \mathbf{R}_n, \mathbf{r}' + \mathbf{R}_{n'}) = \rho(\mathbf{r}, \mathbf{r}' + \mathbf{R}_{n'} - \mathbf{R}_n) = \rho_{\mathbf{r}, \mathbf{r}'}(\mathbf{R}_{n'} - \mathbf{R}_n) \quad (4.93)$$

The notation $\rho_{\mathbf{r}, \mathbf{r}'}(\mathbf{R}_n)$ for the one-electron DM in the coordinate representation implies that the indices $\mathbf{r}$ and $\mathbf{r}'$ of the matrix vary continuously only within the primitive cell. Therefore, there is an analogy between the properties of the DM in the coordinate representation and the properties of the DM represented in terms of a set of basis functions, for example, in terms of Bloch sums of atomic orbitals (AOs) or plane waves.

As is known, the diagonal elements of the one-electron DM in the coordinate representation are equal to the electron density:

$$\rho(\mathbf{R}) = \rho(\mathbf{R}, \mathbf{R}) = \rho_{r,r}(0) \quad (4.94)$$

From the normalization condition for the many-electron wavefunction within the basic domain, it follows that

$$\int_{V_N} \rho(\mathbf{R}, \mathbf{R}) d^3\mathbf{R} = Nn = \sum_{\mathbf{R}_n} \int_{V_a} \rho_{r,r}(0) d^3\mathbf{r} = N \int_{V_a} \rho_{r,r}(0) d^3\mathbf{r} \quad (4.95)$$

Therefore, the electron density is normalized to the number of electrons per primitive cell:

$$\int_{V_a} \rho_{r,r}(0) d^3\mathbf{r} = n \quad (4.96)$$

By using the single-determinant approximation to the many-electron wavefunction, the DM can be expressed through the one-electron wavefunctions (crystalline orbitals):

$$\rho(\mathbf{R}, \mathbf{R}') = \sum_i \sum_{\mathbf{k}} n_i(\mathbf{k}) \varphi_{i\mathbf{k}}(\mathbf{R}) \varphi_{i\mathbf{k}}^*(\mathbf{R}') \quad (4.97)$$

where the index i specifies the energy bands and $n_i(\mathbf{k})$ are the occupation numbers. In nonconducting crystals, the energy bands are either completely filled or empty; therefore, $n_i(\mathbf{k})$ are independent of $\mathbf{k}$ and $n_i = 0, 2$.

The one-electron DM is invariant under any orthogonal transformation in the space of occupied states. In particular, in nonconducting crystals, we can go over from the orthonormal set of extended Bloch states $\varphi_{i\mathbf{k}}(\mathbf{R})$ to the orthonormal set of localized Wannier functions (see Chap. 3):

$$W_i(\mathbf{R} - \mathbf{R}_n) = \sqrt{\frac{1}{N}} \sum_{\mathbf{k}} \exp(i\mathbf{k} \cdot \mathbf{R}_n) \varphi_{i\mathbf{k}}(\mathbf{R}) \quad (4.98)$$

In this case, (4.97) for the DM takes the form

$$\rho(\mathbf{R}, \mathbf{R}') = \sum_i n_i \sum_{\mathbf{R}_m} W_i(\mathbf{R} - \mathbf{R}_m) W_i^*(\mathbf{R}' - \mathbf{R}_m) \quad (4.99)$$

or

$$\rho_{r,r'}(\mathbf{R}_n) = \sum_i n_i \sum_{\mathbf{R}_m} W_i(\mathbf{r} - \mathbf{R}_m) W_i^*(\mathbf{r}' - \mathbf{R}_m + \mathbf{R}_n) \quad (4.100)$$

It is well known that the Wannier functions $W_i(\mathbf{R})$ vanish exponentially as $|\mathbf{R}| \rightarrow \infty$ in crystals with completely filled bands. Since the vectors $\mathbf{r}$ and $\mathbf{r}'$ lie in the reference (zeroth) primitive unit cell, the products of the Wannier functions on

the right-hand side of (4.100) fall off exponentially with increasing $|\mathbf{R}_n|$. Therefore, we may expect the total lattice sum in (4.100) for the offdiagonal elements $\rho_{r,r'}(\mathbf{R}_n)$ of the DM to also vanish exponentially with increasing $|\mathbf{R}_n|$. It should be noted that in metals, the DM decays according to a power law.

Under translation through a lattice vector, according to Bloch's theorem, the crystal orbitals transform according to irreducible representations of the translation group

$$\varphi_{ik}(\mathbf{R} + \mathbf{R}_n) = \exp(-i\mathbf{k} \cdot \mathbf{R}_n) \varphi_{ik}(\mathbf{R}) \quad (4.101)$$

This condition is satisfied for both the infinite crystal and the basic domain; only the sets of values of the wavevector $\mathbf{k}$ for which (4.101) is satisfied are different in these two cases. By applying Bloch's theorem (4.101) to the wavefunctions in (4.97) for the one-electron DM of the basic domain, we obtain

$$\rho_{r,r'}(\mathbf{R}_n) = \sum_i \sum_{\mathbf{k}} n_i(\mathbf{k}) \varphi_{ik}(\mathbf{r}) \varphi_{ik}^*(\mathbf{r}' + \mathbf{R}_n) = \frac{1}{N} \sum_{\mathbf{k}} \exp(-i\mathbf{k} \cdot \mathbf{R}_n) P_{r,r'}(\mathbf{k}) \quad (4.102)$$

where $P_{r,r'}(\mathbf{k})$ is the density matrix in $\mathbf{k}$ -space, which is defined as

$$P_{r,r'}(\mathbf{k}) = N \sum_i n_i(\mathbf{k}) \varphi_{ik}(\mathbf{r}) \varphi_{ik}^*(\mathbf{r}') \quad (4.103)$$

From the familiar orthogonality relations for columns and rows of the matrices in the irreducible representations of the Abelian translation group, it follows that

$$\frac{1}{N} \sum_{\mathbf{R}_n} \exp(i\mathbf{k} \cdot \mathbf{R}_n) = \delta_{\mathbf{k},\mathbf{b}}; \quad \frac{1}{N} \sum_{\mathbf{k}} \exp(i\mathbf{k} \cdot \mathbf{R}_n) = \delta_{\mathbf{R}_n,\mathbf{A}} \quad (4.104)$$

where $\mathbf{b}$ is a reciprocal lattice vector and $\mathbf{A}$ is a primitive translation of the basic domain as a whole. Using (4.104), it is easy to derive an inverse relation of (4.102):

$$P_{r,r'}(\mathbf{k}) = \sum_{\mathbf{R}_n} \exp(i\mathbf{k} \cdot \mathbf{R}_n) \rho_{r,r'}(\mathbf{R}_n) \quad (4.105)$$

It follows from (4.105) that $P_{r,r'}(\mathbf{k})$ is a periodic function in the reciprocal space

$$P_{r,r'}(\mathbf{k} + \mathbf{b}_m) = P_{r,r'}(\mathbf{k}) \quad (4.106)$$

Using the hermiticity of the DM

$$\rho(\mathbf{R}, \mathbf{R}') = \rho^*(\mathbf{R}', \mathbf{R}) \quad (4.107)$$

we find that

$$\rho_{r,r'}(\mathbf{R}_n) = \rho_{r',r}^*(-\mathbf{R}_n); \quad P_{r,r'}(\mathbf{k}) = P_{r',r}^*(-\mathbf{k}) \quad (4.108)$$

From (4.96), the normalization condition for the DM in $\mathbf{k}$ -space can easily be found to be

$$\int_{V_a} P_{r,r}(\mathbf{k}) d^3\mathbf{r} = n \quad (4.109)$$

Here, the integration is performed over a primitive cell of volume V_a .

In the case where the many-electron wavefunction is calculated in the single-determinant approximation, the spinless DM is duodempotent:

$$\int_{V_N} \rho(\mathbf{R}, \mathbf{R}'') \rho(\mathbf{R}'', \mathbf{R}') d^3\mathbf{R}'' = 2\rho(\mathbf{R}, \mathbf{R}') \quad (4.110)$$

Similar relations also hold for the matrices $\rho_{r,r'}(\mathbf{R}_n)$ and $P_{r,r'}(\mathbf{k})$:

$$\sum_{\mathbf{R}_m} \int_{V_a} d^3\mathbf{r}'' \rho_{r,r''}(\mathbf{R}_m) \rho_{r'',r'}(\mathbf{R}_n - \mathbf{R}_m) = 2\rho_{r,r'}(\mathbf{R}_n) \quad (4.111)$$

$$\int_{V_a} d^3\mathbf{r}'' P_{r,r''}(\mathbf{k}) P_{r'',r'}(\mathbf{k}) = 2P_{r,r'}(\mathbf{k}) \quad (4.112)$$

The one-electron density matrix has the same point-symmetry group F as the crystal structure.

Let operator $\hat{g} = t_v R$ correspond to the coset representative $t_v R$ in the coset decomposition of the crystal-structure space group G over translation subgroup T (see (2.15)). In this notation, the density-matrix point symmetry can be written in the form

$$\hat{g}\rho(\mathbf{R}, \mathbf{R}') = \rho(\hat{g}^{-1}\mathbf{R}, \hat{g}^{-1}\mathbf{R}') = \rho(\mathbf{R}, \mathbf{R}') \quad (4.113)$$

For the density matrix $\rho_{rr'}(\mathbf{R}_n)$ in the direct space, we can write

$$\hat{g}\rho_{rr'}(\mathbf{R}_n) = \rho_{\hat{g}^{-1}\mathbf{r} + \mathbf{R}_n, \hat{g}^{-1}\mathbf{r}' + \mathbf{R}'_n}(\mathbf{R}_n) = \rho_{rr'}(\mathbf{R}_n) \quad (4.114)$$

where $\mathbf{R}_m$ is the translation vector that returns $\hat{g}^{-1}\mathbf{r}$ back to the reference unit cell. In a similar manner, the $\mathbf{R}'_n$ vector returns $\hat{g}^{-1}\mathbf{r}'$ back to the reference cell. Using relation (4.105) for the DM in the reciprocal space, we obtain

$$\hat{g}P_{rr'}(\mathbf{k}) = \exp[i\mathbf{R}^{-1}\mathbf{k}(\mathbf{r}' - \mathbf{R}_n)] P_{R^{-1}\mathbf{r} + \mathbf{R}_n, R^{-1}\mathbf{r}' + \mathbf{R}'_n}(\mathbf{k}) = P_{rr'}(\mathbf{k}) \quad (4.115)$$

Hence, we have a useful relation between matrix elements of the DM for the star of the wavevector $\mathbf{k}$:

$$P_{rr'}(R\mathbf{k}) = \exp[i\mathbf{k}(\mathbf{R}'_n - \mathbf{R}_n)] P_{R^{-1}\mathbf{r} + \mathbf{R}_n, R^{-1}\mathbf{r}' + \mathbf{R}'_n} \quad (4.116)$$

In practical calculations of the band structure of crystals by the Hartree–Fock method, the one-electron density matrix $P_{rr'}(\mathbf{k})$ in the reciprocal space can be calculated only for a rather small finite set of special points (see Sect. 4.2). Let us consider such a set of special points $\{\mathbf{k}_j\}$, $j = 1, 2, \dots, N_0$. Then, in the calculation of the density matrix of the infinite crystal, the integration over the Brillouin-zone volume V_B is changed by the sum over the special points chosen:

$$\frac{1}{V_B} \int_{V_B} d^3\mathbf{k} P_{rr'}(\mathbf{k}) \cong \frac{1}{N_0} \sum_{\mathbf{k}_j} P_{rr'}(\mathbf{k}_j) \quad (4.117)$$

Thus, the approximate density matrix $\tilde{\rho}(\mathbf{R}, \mathbf{R}')$ is introduced:

$$\begin{aligned} \tilde{\rho}(\mathbf{R}, \mathbf{R}') &= \frac{1}{N_0} \sum_{\mathbf{k}_j} P_{rr'}(\mathbf{k}_j) \\ \tilde{\rho}_{r,r'}(\mathbf{R}_n) &= \frac{1}{N_0} \sum_{\mathbf{k}_j} \exp(-i\mathbf{k} \mathbf{R}_n) P_{r,r'}(\mathbf{k}_j) \end{aligned} \quad (4.118)$$

The approximate density matrix $\tilde{\rho}(\mathbf{R}, \mathbf{R}')$ satisfies the translation-symmetry conditions. This matrix also satisfies the point-symmetry condition, provided that the whole star of each vector $\mathbf{k}_j$ is included in the set of special points $\{\mathbf{k}_j\}$. However, the approximate density matrix $\tilde{\rho}(\mathbf{R}, \mathbf{R}')$ does not satisfy other properties of the exact DM. It is easy to see that an arbitrary finite sum over vectors $\mathbf{k}_j$, of delocalized Bloch functions $\varphi_{i\mathbf{k}_j}(\mathbf{r})$, does not decrease with $|\mathbf{r}| \rightarrow \infty$. Therefore, provided that the $\mathbf{R}$ vector in expression (4.97) for the DM is fixed, the approximate density matrix $\tilde{\rho}$ does not decrease and does not approach zero as $|\mathbf{R} - \mathbf{R}'| \rightarrow \infty$. This incorrect asymptotic of the approximate DM is the reason for the divergence in the calculation of ρ^2 and for the violation of the idempotency conditions. Indeed, using the orthonormality of the set of Bloch functions $\varphi_{i\mathbf{k}}$, it is easy to verify [90] that

$$\hat{\rho}^2 = 2 \frac{N}{N_0} \hat{\rho} \rightarrow \infty \text{ at } N \rightarrow \infty \quad (4.119)$$

The incorrect asymptotic behavior of the approximate density matrix $\tilde{\rho}$ gives rise to divergences in calculations of the average values of some physical quantities. In particular, for the exchange energy per unit cell K_{ex} , we obtain the divergence

$$K_{ex} = \frac{1}{N} \int_{V_N} d^3\mathbf{R} \int_{V_N} d^3\mathbf{R}' \frac{|\tilde{\rho}(\mathbf{R}, \mathbf{R}')|^2}{|\mathbf{R} - \mathbf{R}'|} \rightarrow \infty \text{ at } N \rightarrow \infty \quad (4.120)$$

It was empirically found that, in a calculation of the electron structure of crystals with nonlocal exchange, the integration of the Hartree–Fock exchange potential over the direct lattice requires a so-called exchange-interaction radius to be introduced.

The exchange–interaction radius cannot be arbitrarily large but must correspond to the used number of points $\mathbf{k}$ in the Brillouin zone.

This fact was explained in [90]. It was shown that the use of a finite number of special points and simple cubature formulas for integration over the Brillouin zone leads to an incorrect behavior of the offdiagonal matrix elements of the DM at large distances. This leads to nonphysical divergences in the calculation of the Hartree–Fock nonlocal exchange potential and the Hartree–Fock exchange energy of a crystal. Similar divergences take place in the calculation of the square of the DM. This naturally violates the idempotency of the exact one-electron matrix required of the Hartree–Fock one-determinant method. In the theory of special points, the divergence problem arises only in the cases where the total exchange energy and the exchange potential of the crystal depend on offdiagonal elements of the DM. Thus, in contrast to the Hartree–Fock method, this problem is nonexistent in methods based on density-functional theory; it is precisely the approximation where the theory of special points was first applied. In calculations of the electron structure with nonlocal exchange, this theory must be modified to avoid the above-mentioned divergences (see Sect. 4.3.3). The considered properties of DM (translation and point symmetry, duodempotency and normalization properties) do not depend on the basis choice (LCAO or plane waves). In the next section, we consider the density matrix of a crystal in the LCAO approximation.

4.3.2 The One-Electron Density Matrix of the Crystal in the LCAO Approximation

In Sect. 4.1.5, the Hartree–Fock LCAO approximation for periodic systems was considered. The main difference of the CO LCAO method (crystalline orbitals as linear combination of atomic orbitals) from that used in molecular quantum chemistry, the MO LCAO (molecular orbitals as linear combination of atomic orbitals) method, was explained. In the CO LCAO approximation, the one-electron wavefunction of a crystal (CO - $\varphi_{ik}(\mathbf{R})$) is expanded in Bloch sums $\chi_{\mu k}(\mathbf{R})$ of AOs:

$$\varphi_{ik}(\mathbf{R}) = \sum_{\mu} C_{i\mu}(\mathbf{k}) \chi_{\mu k}(\mathbf{R}) \quad (4.121)$$

where

$$\chi_{\mu k}(\mathbf{R}) = \frac{1}{\sqrt{N}} \sum_{\mathbf{R}_n} \exp(i\mathbf{k} \cdot \mathbf{R}_n) \chi_{\mu}(\mathbf{R} - \mathbf{R}_n) \quad (4.122)$$

In (4.121) and (4.122), the index μ labels all AOs in the reference primitive cell ($\mu = 1, 2, \dots, M$) and the index i numbers the energy bands ($i = 1, 2, \dots, M$). The appearance of energy bands for periodic systems is the result of translation repeating of the primitive unit-cell AO over the infinite crystal of the cyclic system modeling the infinite crystal. In the calculation of the molecular electronic structure,

the MOs are filled by electrons, taking into account the degeneracy of levels due to the point-symmetry group. In crystals, COs are filled by electrons, and the degeneracy of one-electron states is defined by irreps of the space-symmetry group of a crystal. This means that the one-electron energy bands are filled by electrons, and for nonconducting crystals, the valence bands are filled and the conduction bands are empty.

The Bloch sums (4.121) of AOs, as well as the AOs, do not constitute an orthonormal basis, that is, the overlap integrals

$$\begin{aligned} S_{\mu\nu}(\mathbf{k}) &= \int d^3\mathbf{R} \chi_{\mu\mathbf{k}}^*(\mathbf{R}) \chi_{\nu\mathbf{k}}(\mathbf{R}) \\ s_{\mu\nu}(\mathbf{R}_n) &= \int d^3\mathbf{R} \chi_{\mu}^*(\mathbf{R}) \chi_{\nu}(\mathbf{R} - \mathbf{R}_n) \end{aligned} \quad (4.123)$$

are not equal to $\delta_{\mu\nu}$.

The crystalline orbitals $\varphi_{i\mathbf{k}}(\mathbf{r})$ compose an orthonormal set from which the following orthonormality relations can be derived for the elements of the matrix $\mathbf{C}(\mathbf{k})$ involved in (4.57):

$$\{\mathbf{C}(\mathbf{k})\mathbf{S}(\mathbf{k})\mathbf{C}(\mathbf{k})\}_{ij} = \delta_{ij} \quad (4.124)$$

In terms of the Bloch sums of AOs, the DM elements $P_{\mu\nu}(\mathbf{k})$ can be expressed as

$$P_{\mu\nu}(\mathbf{k}) = \sum_i n_i(\mathbf{k}) C_{i\mu}(\mathbf{k}) C_{i\nu}^*(\mathbf{k}) \quad (4.125)$$

Within the LCAO approximation, the DM elements in the coordinate space are given by an expression similar to (4.101):

$$\rho_{\mu\nu}(\mathbf{R}_n) = \frac{1}{N} \sum_{\mathbf{k}} \exp(-i\mathbf{k} \cdot \mathbf{R}_n) P_{\mu\nu}(\mathbf{k}) \quad (4.126)$$

and the DM in the reciprocal space is related to the DM in the direct (coordinate) space through a relation similar to (4.105):

$$P_{\mu\nu}(\mathbf{k}) = \sum_{\mathbf{R}_n} \exp(i\mathbf{k} \cdot \mathbf{R}_n) \rho_{\mu\nu}(\mathbf{R}_n) \quad (4.127)$$

In the reciprocal space, the analog of the normalization condition (4.109) for the DM in the AO representation is the relation:

$$Sp(\mathbf{P}(\mathbf{k})\mathbf{S}(\mathbf{k})) = \sum_{\mu\nu} P_{\mu\nu}(\mathbf{k}) S_{\mu\nu}(\mathbf{k}) = n \quad (4.128)$$

The normalization condition for the DM in the coordinate space (analog of (4.95)) is

$$\sum_{\mathbf{R}_n} S p [\rho(\mathbf{R}_n) s(-\mathbf{R}_n)] = n \quad (4.129)$$

The idempotency relation for the density matrix $P(\mathbf{k})$ in the reciprocal space (with allowance for the nonorthogonality of the basis) has the form ($n_i(\mathbf{k}) = 0, 2$):

$$P(\mathbf{k})S(\mathbf{k})P(\mathbf{k}) = 2P(\mathbf{k}) \quad (4.130)$$

In the coordinate space, the idempotency relation for the DM is written as

$$\sum_{\mathbf{R}_m, \mathbf{R}'_m} \rho(\mathbf{R}_m) S(\mathbf{R}'_m - \mathbf{R}_m) \rho(\mathbf{R}_n - \mathbf{R}'_m) = 2\rho(\mathbf{R}_n) \quad (4.131)$$

In various semiempirical versions of the Hartree–Fock approximation (see Chap. 6), the orthonormal set of Löwdin atomic orbitals (LAOs) rather than the nonorthogonal AO basis is used; the LAOs are defined as

$$\chi_{\mu\mathbf{k}}^L(\mathbf{R}) = \sum_{\nu} S_{\mu\nu}^{-1/2}(\mathbf{k}) \chi_{\nu\mathbf{k}}(\mathbf{R}) \quad (4.132)$$

In this basis, the normalization condition for the density matrix $P^L(\mathbf{k})$ is simplified; instead of (4.129) we have

$$S p P^L(\mathbf{k}) = n, \quad S p \rho^L(0) = n \quad (4.133)$$

In the LCAO basis, the idempotency relations for the DM in the coordinate and reciprocal spaces are similar to (4.128) and (4.129) for the DM in the coordinate representation; in the reciprocal space, we have

$$P^L(\mathbf{k})P^L(\mathbf{k}) = 2P^L(\mathbf{k}) \quad (4.134)$$

and in the coordinate space, the relation has the form

$$\sum_{\mathbf{R}_m} \rho^L(\mathbf{R}_m) \rho^L(\mathbf{R}_n - \mathbf{R}_m) = 2\rho^L(\mathbf{R}_n) \quad (4.135)$$

In particular, for the reference primitive cell ($\mathbf{R}_n = 0$), with allowance for the hermiticity of the DM, we have

$$\sum_{\mathbf{R}_n} \rho^L(\mathbf{R}_n) \rho^{L*}(\mathbf{R}_n) = 2\rho^L(0) \quad (4.136)$$

The offdiagonal elements of the DM in the AO basis determine the quantities

$$W_{AB}(\mathbf{R}_n) = \sum_{\mu \in A, \nu \in B} |\rho_{\mu\nu}^L(\mathbf{R}_n)|^2 \quad (4.137)$$

that can be considered as the extension to the crystals of the Wiberg indices introduced for molecules [91]. The Wiberg indices $W_{AB}(\mathbf{R}_n)$ can be interpreted as chemical-bond indices (orders) between atoms A and B, belonging to the reference and $\mathbf{R}_n$ th primitive cells, respectively [92,93]. These indices are subject to a relation that is a consequence of the idempotency of the DM. To derive this relation, we consider the diagonal matrix elements of (4.136) and carry out summation over all AO indices of atom A. The result is

$$\sum_{B \neq A} \sum_{\mathbf{R}_n} W_{AB}(\mathbf{R}_n) = 2\rho_A^L - \sum_{\mu \in A} \rho_{\mu\mu}^L(0) \quad (4.138)$$

Here, ρ_A^L is the total electron population (in Lowdin's sense) of atom A:

$$\rho_A^L = \sum_{\mu} \rho_{\mu\mu}^L(0) \quad (4.139)$$

Let us define the covalence C_A of atom A as the sum of the chemical-bond orders (Wiberg indices) between atom A and all other atoms of the crystal. Using the idempotency relation (4.138), we have

$$C_A = \sum_{B, \mathbf{R}_n \neq A, 0} W_{AB}(\mathbf{R}_n) = 2\rho_A^L - \sum_{\mu \in A} \rho_{\mu\mu}^L(0) \quad (4.140)$$

It follows from (4.140) that the covalence of atom A in the crystal can be calculated either by summing the bond indices between atom A and all other atoms of the crystal or by using only single-center DM elements related to atom A. This property of the covalence is a consequence of the idempotency of the DM.

The Wiberg indices (4.137) and atomic covalence (4.140) are called the local properties of the electronic structure of periodic systems. These properties also include AO populations, atomic charges (electrovalencies), and total atomic valences [92]. The analysis of the local properties of the electronic structure in molecular quantum chemistry is very popular as it gives useful information about the chemical bonding. The local properties of the electronic structure of crystals are considered in more detail in Chap. 9. The above consideration holds for the density matrix of the basic domain of the crystal, that is, it is assumed that the number N of primitive cells in this domain is so large that the introduction of cyclic boundary conditions virtually does not affect the density matrix of the infinite crystal.

In actual practice, the SCF calculations of periodic systems are made with the approximate DM $\tilde{\rho}(\mathbf{R}, \mathbf{R}')$, which is calculated by summation in (4.102) over a finite (relatively small) number of $\mathbf{k}$ -points. As a result, the divergence of the summation in the direct lattice can appear in the nonlocal exchange part of the Fock matrix. This problem is considered in the next section.

4.3.3 *Interpolation Procedure for Constructing an Approximate Density Matrix for Periodic Systems*

Let the electronic structure of a crystal be calculated using the one-electron wavefunctions found at a finite number L of points $\{\mathbf{k}_j\}$ in the BZ ($j = 1, 2, \dots, L$). This raises the question of how the sum over $\mathbf{k}$ -points in the BZ should be approximately calculated in (4.102) for the one-electron DM of the crystal.

We consider a set of points $\{\mathbf{k}_j\}$ generated by the large unit cell (LUC)–small Brillouin zone (SBZ) method; see Sect. 4.2.2. In this method, the primitive lattice vectors $\mathbf{a}_i$ ($i = 1, 2, 3$) are transformed with the aid of a matrix $\mathbf{l}$ whose elements are integers (see (4.77)):

$$\mathbf{A}_j^L = \sum_{i=1}^3 l_{ji} \mathbf{a}_i, \quad L = |\det \mathbf{l}| \quad (4.141)$$

The basis vectors $\mathbf{A}_j^L$ determine an LUC and a new Bravais superlattice. The LUC thus constructed has volume $V_L = L V_a$ and consists of L primitive cells. The superlattice vectors $\mathbf{A}$ are linear combinations (with integral-valued coefficients) of the basis vectors $\mathbf{A}_j^L$. The matrix $\mathbf{l}$ in (4.141) is chosen such that the point symmetry of the new superlattice is identical to that of the original lattice (the corresponding transformation (4.141) is called a symmetric transformation; see Sect. 4.2.1). The type of direct lattice can be changed if there are several types of lattice with the given point symmetry. The LUC is conveniently chosen in the form of a Wigner–Seitz (WS) cell, which possesses the point symmetry of the lattice.

We introduce the periodic boundary conditions for the crystal domain coinciding with the LUC, that is, we assume that all translations through the superlattice vectors $\mathbf{A}$ are equivalent to the identity translation. Thus, we have a system of finite size, *that is*, a cyclic cluster belonging to the symmetry group $G^L = T^L F$; see Sect. 2.2.3 (we consider only symmetric transformations). Here, the subgroup T^L includes L translations through the vectors $\mathbf{R}_n^0$ of inner translations of the original direct lattice that lie within the LUC or fall on its boundary. The lattice sites lying on the boundary of the LUC are connected by superlattice vectors $\mathbf{A}$. These lattice sites should be counted only once because they belong simultaneously to several LUCs.

For the cyclic cluster thus constructed, the following orthogonality relations hold:

$$\frac{1}{L} \sum_{\mathbf{R}_n^0} \exp(i\mathbf{k}_j \mathbf{R}_n^0) = \delta_{\mathbf{k}, \mathbf{b}} \quad (4.142)$$

$$\frac{1}{L} \sum_{\mathbf{k}_j} \exp(-i\mathbf{k}_j \mathbf{R}_n^0) = \delta_{\mathbf{R}_n^0, \mathbf{A}} \quad (4.143)$$

These relations are a generalization of the analogous equations for the basic domain of the crystal because the cyclic cluster is obtained with the help of

transformation (4.141), in which the matrix l can be nondiagonal. The vectors $\mathbf{k}_j$ in (4.142) and (4.143) label L different irreducible representations of the group T^L and can be found from the relation

$$\exp(i\mathbf{k}_j \mathbf{A}) = 1, \quad (j = 1, 2, \dots, L) \quad (4.144)$$

Equation (4.142) is a consequence of the orthogonality of the characters of irreducible representations of the translation group to the character of the unit representation ($\mathbf{k} = 0$), while (4.143) means that the characters of a regular representation of the group are equal to zero for all elements of the group except for the identity element (*i.e.*, except for the identity translation and equivalent translations through the superlattice vectors $\mathbf{A}$).

Let the density matrix $P(\mathbf{k})$ be known at a finite set of points determined by the LUC–SBZ method and, therefore, satisfying (4.144). Our aim is to approximate the DM at an arbitrary point $\mathbf{k}$ in the BZ. The interpolation procedure suggested in [67] and discussed in this subsection is appropriate for calculations in both the coordinate representation and the AO basis. For this reason, we drop the indices on the DM, keeping in mind that these indices are $\mathbf{r}$ and $\mathbf{r}'$ in the coordinate representation and μ and ν in the AO or orthogonalized-AO representation.

The expansions of the density matrix $P(\mathbf{k})$ given by (4.105) and (4.127) can be rewritten in the form

$$P(\mathbf{k}) = \sum_{\mathbf{R}_n^0} \exp(i\mathbf{k} \mathbf{R}_n^0) \rho(\mathbf{R}_n^0) + \sum_{\mathbf{A} \neq 0} \sum_{\mathbf{R}_n^0} \exp(i\mathbf{k}(\mathbf{R}_n^0 + \mathbf{A})) \rho(\mathbf{R}_n^0 + \mathbf{A}) \quad (4.145)$$

where the translations $(\mathbf{R}_n^0 + \mathbf{A})$ lie in the basic domain of the crystal. As mentioned in Sect. 4.3.2, the offdiagonal elements of the density matrix $\rho(\mathbf{R}_n^0 + \mathbf{A})$ fall off with distance as Wannier functions (exponentially in the case of insulators). Therefore, as the LUC grows in size and the values of $|\mathbf{A}|$ become sufficiently large, the second term in (4.145) will be small in magnitude. With this in mind, we will approximate the density matrix $\tilde{P}(\mathbf{k})$ of the crystal as follows [67]. In the expansion given by (4.145), we drop the sum over the superlattice sites with $\mathbf{A} \neq 0$ and take the remaining expression as an interpolation formula for determining the DM at any $\mathbf{k}$ -point in the BZ; we rewrite this expression in the form

$$\tilde{P}(\mathbf{k}) = \sum_{\mathbf{R}_n^0} \exp(i\mathbf{k} \mathbf{R}_n^0) \rho^0(\mathbf{R}_n^0) \quad (4.146)$$

This formula was proposed in [67] for the interpolation of an arbitrary periodic function $f(\mathbf{k})$. The interpolation coefficients $\rho^0(\mathbf{R}_n^0)$ (the number of which is L) can be found from the condition

$$\tilde{P}(\mathbf{k}_j) = \sum_{\mathbf{R}_n^0} \exp(i\mathbf{k}_j \mathbf{R}_n^0) \rho^0(\mathbf{R}_n^0) = P(\mathbf{k}_j) \quad (4.147)$$

Using the orthogonality relation (4.143), the interpolation coefficients can be found to be

$$\rho^0(\mathbf{R}_n^0) = \frac{1}{L} \sum_{\mathbf{k}_j} \exp(-i\mathbf{k}_j \mathbf{R}_n^0) P(\mathbf{k}_j) \quad (4.148)$$

The coefficients $\rho^0(\mathbf{R}_n^0)$ can also be represented as a sum of the DM elements $\rho(\mathbf{R}_n^0)$ over the superlattice sites. Indeed, substituting (4.146) for $P(\mathbf{k}_j)$ into (4.148) and using (4.143), we have

$$\rho^0(\mathbf{R}_n^0) = \sum_A \rho(\mathbf{R}_n^0 + \mathbf{A}) \quad (4.149)$$

It should be noted that the matrix $\rho^0(\mathbf{R}_n^0)$ can be defined for all vectors $\mathbf{R}_n$ of the Bravais lattice by using the appropriate extensions of (4.148) and (4.149). It is easy to see that $\rho^0(\mathbf{R}_n^0)$ is a periodic function of period $\mathbf{A}$. Substituting (4.148) for the coefficients $\rho^0(\mathbf{R}_n^0)$ into (4.149), we obtain an interpolation formula for the DM in the reciprocal space:

$$\tilde{P}(\mathbf{k}) = \sum_{\mathbf{k}_j} P(\mathbf{k}_j) \Omega_j(\mathbf{k}) \quad (4.150)$$

$$\Omega_j(\mathbf{k}) = \frac{1}{L} \sum_{\mathbf{R}_n^0} \exp(i(\mathbf{k} - \mathbf{k}_j) \mathbf{R}_n^0) \quad (4.151)$$

Here, $\Omega_j(\mathbf{k})$ are interpolation weights, the sum of which is equal to unity (the normalization natural for weighting factors). Indeed, using (4.143), we find

$$\sum_{\mathbf{k}_j} \Omega_j(\mathbf{k}) = \sum_{\mathbf{R}_n^0} \exp(i\mathbf{k} \mathbf{R}_n^0) \left[\frac{1}{L} \sum_{\mathbf{k}_j} \exp(-i\mathbf{k}_j \mathbf{R}_n^0) \right] = \sum_{\mathbf{R}_n^0} \exp(i\mathbf{k} \mathbf{R}_n^0) \delta_{\mathbf{R}_n^0, 0} = 1 \quad (4.152)$$

For the appropriate DM in the coordinate space, one can write equations similar to (4.118) and (4.133):

$$\tilde{\rho}(\mathbf{R}_n) = \frac{1}{N} \sum_{\mathbf{k}} \exp(-i\mathbf{k} \mathbf{R}_n) \tilde{P}(\mathbf{k}) = \sum_{\mathbf{R}_n^0} \rho^0(\mathbf{R}_n^0) \left[\frac{1}{N} \sum_{\mathbf{k}} \exp(i\mathbf{k} (\mathbf{R}_n^0 - \mathbf{R}_n)) \right] \quad (4.153)$$

According to (4.143), the expression in the square brackets on the right-hand side of (4.153) is equal to unity if the vector $\mathbf{R}_n$ belongs to the set of vectors $\{\mathbf{R}_n^0\}$ (*i.e.*, if this vector lies within the LUC or on its boundary) and vanishes otherwise. Therefore, the appropriate DM can be represented in the form

$$\tilde{\rho}(\mathbf{R}_n) = \omega(\mathbf{R}_n) \rho^0(\mathbf{R}_n) \quad (4.154)$$

where $\omega(\mathbf{R}_n)$ is the so-called weighting function

$$\omega(\mathbf{R}_n) = \frac{1}{N} \sum_k \exp(i\mathbf{k}(\mathbf{R}_n^0 - \mathbf{R}_n)) = \begin{cases} 1, & \text{if } \mathbf{R}_n \in \{\mathbf{R}_n^0\} \\ 0, & \text{if } \mathbf{R}_n \notin \{\mathbf{R}_n^0\} \end{cases} \quad (4.155)$$

We note that the procedure described above for interpolating the DM in the BZ is not uniquely determined because the LUC (*i.e.*, the set of vectors $\{\mathbf{R}_n^0\}$) can be variously chosen for the same superlattice. Furthermore, the LUC can be chosen differently for the pairs of DM indices $\mathbf{r}, \mathbf{r}'$, and μ, ν . In this book, the LUC is taken to be the Wigner–Seitz cell because only this cell has a symmetry identical to the point symmetry of the superlattice in all cases. In order to correlate the LUC with a cyclic cluster, we choose the LUC to be dependent on the pair of DM indices as follows. In the coordinate representation, the LUC (V_A -region) is centered at the point $(\mathbf{r} - \mathbf{r}')$; therefore, we have

$$\omega_{\mathbf{r}\mathbf{r}'}(\mathbf{R}_n) = \omega(\mathbf{R}_n + \mathbf{r}' - \mathbf{r}) = \begin{cases} 1, & \text{if } \mathbf{R}_n + \mathbf{r}' - \mathbf{r} \in V_A \\ 0, & \text{if } \mathbf{R}_n + \mathbf{r}' - \mathbf{r} \notin V_A \end{cases} \quad (4.156)$$

In the AO representation, the LUC is centered at the point $\mathbf{d}_\mu - \mathbf{d}_\nu$ where $\mathbf{d}_\mu$ and $\mathbf{d}_\nu$ are the position vectors of the two atoms to which the AOs with indices μ and ν belong, respectively. Thus, we have

$$\omega_{\mu\nu}(\mathbf{R}_n) = \omega(\mathbf{R}_n + \mathbf{d}_\nu - \mathbf{d}_\mu) = \begin{cases} 1, & \text{if } \mathbf{R}_n + \mathbf{d}_\nu - \mathbf{d}_\mu \in V_A \\ 0, & \text{if } \mathbf{R}_n + \mathbf{d}_\nu - \mathbf{d}_\mu \notin V_A \end{cases} \quad (4.157)$$

The weighting function $\omega_{\mu\nu}(\mathbf{R}_n)$ of (4.157) introduced into expressions for the DM specifies the cyclic boundary conditions and the cyclic cluster. Indeed, let an arbitrarily chosen LUC be fixed and let us consider the orbitals of atoms A and B in this LUC ($\mu \in A, \nu \in B$). Out of all matrix elements $\tilde{\rho}_{\mu\nu}(\mathbf{R}_n + \mathbf{A})$ with indices μ and ν kept fixed and the vector $\mathbf{A}$ running over the superlattice, only one matrix element is nonzero. For this matrix element, the vector $(\mathbf{d}_\nu + \mathbf{R}_n + \mathbf{A})$ (the position vector of atom B) falls into the Wigner–Seitz cell centered at atom A site. This matrix element exactly equals the matrix element $\rho_{\mu\nu}^0(\mathbf{R}_n)$.

According to (4.154), the approximate density matrix $\tilde{\rho}(\mathbf{R}_n)$ found by interpolation in the BZ contains the weighting function of (4.155)–(4.157) as a factor. This function ensures the proper behavior of the offdiagonal elements of the approximate DM as $|\mathbf{R}_n| \rightarrow \infty$. As already mentioned, the matrix without a weighting factor is a periodic (not vanishing at infinity) function

$$\rho^0(\mathbf{R}_n + \mathbf{A}) = \rho^0(\mathbf{R}_n) \quad (4.158)$$

However, this DM is frequently used in many calculations based on the Hartree–Fock approximation or its semiempirical (with nonlocal exchange) versions for

crystals (the CNDO and INDO methods; see Chap. 6). In those calculations, all summations over the lattice sites are usually truncated by introducing artificially interaction ranges. The non decaying density matrix $\rho^0(\mathbf{R}_n)$ gives rise to a divergent exchange term in the Fock matrix. In other words, as the corresponding interaction range increases in size at a fixed number of involved $\mathbf{k}$ -points, the results do not converge to a certain limit and the total energy of the system sharply decreases.

In order to avoid these divergences, *the exchange-interaction range should be chosen such that the corresponding sphere differs only slightly from the Wigner–Seitz cell of the superlattice*, which generates precisely the set of $\mathbf{k}$ -points used in the calculations. In this case, the size of the summation domain in the coordinate space is in accord with the number of $\mathbf{k}$ -points used in the calculations, and the exchange term in the HF operator does not diverge. The approximate density matrix $\tilde{\rho}^0(\mathbf{R}_n)$ is not subject to these drawbacks, and the balance between the size of the summation domain in the coordinate space and the number of $\{\mathbf{k}_j\}$ points involved occurs automatically.

It should be noted that in the versions of the density-functional theory in which the exchange–correlation term depends on the electron density alone, both approaches are equivalent. Indeed, the electron density $\rho(\mathbf{R}, \mathbf{R}) = \rho_{rr}(0)$ depends only on the diagonal elements of the DM; therefore, the weighting function of (4.155) and (4.156) is equal to unity in this case.

In general, the approximate DM does not satisfy all the conditions to which the exact DM is subject. Let us elucidate which of the relations presented in Sect. 4.2.2 holds for the approximate DM and which does not.

The normalization conditions (4.95), (4.128), and (4.129) are very important. The approximate DM in the coordinate representation and in the LAO basis meets these conditions because the weighting function for the diagonal elements of the DM is equal to unity. In the nonorthogonal basis, a modified normalization condition is satisfied:

$$\sum_{\mathbf{R}_n} \text{Sp} [\tilde{\rho}(\mathbf{R}_n) \tilde{s}(-\mathbf{R}_n)] = n \quad (4.159)$$

where $\tilde{s}(\mathbf{R}_n)$ is an approximate overlap-integral matrix, which is obtained by interpolating in the BZ in much the same way as the approximate DM was obtained and has the form

$$\tilde{s}_{\mu\nu}(\mathbf{R}_n) = \omega(\mathbf{R}_n + \mathbf{d}_\nu - \mathbf{d}_\mu) s_{\mu\nu}^0(\mathbf{R}_n) \quad (4.160)$$

$$s_{\mu\nu}^0(\mathbf{R}_n) = \frac{1}{L} \sum_{\mathbf{k}_j} \exp(-\mathbf{k}_j \mathbf{R}_n) S(\mathbf{k}_j) = \sum_{\mathbf{A}} s(\mathbf{R}_n + \mathbf{A}) \quad (4.161)$$

It is easy to verify that in all cases, the approximate DM is Hermitian, *that is*, it obeys relations identical to (4.107) and (4.108).

In general, the approximate DM is not idempotent because (4.112) holds only at points $\mathbf{k} = \mathbf{k}_j$ ($j = 1, 2, \dots, L$) and is not satisfied at other points of the BZ. For this reason, (4.111) and (4.136) in the coordinate space do not generally hold.

However, in the important particular case where the vector $\mathbf{R}_n$ in these equations is zero, the idempotency relation is satisfied. In the coordinate space and in the LAO representation, we have

$$\sum_{\mathbf{R}_m} \tilde{\rho}(\mathbf{R}_m) \tilde{\rho}(-\mathbf{R}_m) = 2\tilde{\rho}(0) \quad (4.162)$$

Therefore, the important relation for the Wiberg indices (4.140) is also satisfied. We note that the matrix $\rho^0(\mathbf{R}_n)$ obeys the relation

$$\sum_{\mathbf{R}_m^0} \rho^0(\mathbf{R}_m^0) \rho^0(\mathbf{R}_n^0 - \mathbf{R}_m^0) = 2\rho^0(\mathbf{R}_n^0) \quad (4.163)$$

In the strict sense, (4.162) is not an idempotency relation because summation is carried out only over the vectors $\mathbf{R}_m^0$, lying within the LUC, whereas the vector difference $(\mathbf{R}_n^0 - \mathbf{R}_m^0)$ can lie outside the LUC. If we perform summation over all Bravais lattice vectors, the right-hand side of (4.162) will diverge because $\rho^0(\mathbf{R}_n^0)$ does not vanish at infinity.

For the approximate DM to have the proper point symmetry, the LUC should be taken to be the Wigner–Seitz (WS) cell. In this case, however, the symmetry can be broken if on the boundary of the WS cell, there are atoms of the crystal. Indeed, if an atom lies on the WS cell boundary, then there is one or several equivalent atoms that also lie on the boundary of the cell and their position vectors differ from that of the former atom by a superlattice vector $\mathbf{A}$. When constructing the approximate density matrix $\tilde{\rho}$, we assigned only one of several equivalent atoms to the WS cell. In other words, in the set $\{\mathbf{R}_n^0\}$, there are no two vectors that differ from each other by a superlattice vector $\mathbf{A}$. In this case, if a point-symmetry operation takes one boundary atom into another atom assigned to another WS cell, then the point symmetry of the density matrix $\tilde{\rho}$ is broken because the symmetry of the weighting function $\omega_{\mu\nu}(\mathbf{R}_n)$ of (4.157) is broken.

Since it is desirable to preserve the point symmetry when calculating the electronic structure, the approximate DM can be replaced by an averaged density matrix (see also [94,95]):

$$\rho^s = \frac{1}{N_s} \sum_{\alpha=1}^{N_s} \tilde{\rho}^\alpha(\mathbf{R}_n) = \omega^s(\mathbf{R}_n) \rho^0(\mathbf{R}_n) \quad (4.164)$$

Here, the index $\alpha = 1, 2, \dots, N_s$ labels all N_s possible ways in which one of the equivalent boundary atoms can be assigned to a given WS cell and the symmetrical weighting function is defined as

$$\omega_{\mu\nu}^s(\mathbf{R}_n) = \frac{1}{N_s} \sum_{\alpha=1}^{N_s} \omega_{\mu\nu}^\alpha(\mathbf{R}_n) = \begin{cases} \frac{1}{n_{\mu\nu}^s}, & \text{if } \mathbf{R}_n + \mathbf{d}_\nu - \mathbf{d}_\mu \in V_A \\ 0, & \text{if } \mathbf{R}_n + \mathbf{d}_\nu - \mathbf{d}_\mu \notin V_A \end{cases} \quad (4.165)$$

where $n_{\mu\nu}^s$ is the number of atoms in the WS cell (including its boundary) that are translationally equivalent to atom B ($\nu \in B$) in the case where the WS cell is centered at the atom- A site ($\mu \in A$). In other words, $n_{\mu\nu}^s$ is the number of WS cells that have atom B in common. If atom B is strictly inside the WS cell, then $n_{\mu\nu}^s = 1$, and (4.165) is identical to (4.157). We note that the density matrix $\rho^s(\mathbf{R}_n)$ does not satisfy idempotency relation (4.162) and corresponds to a mixed state of the system. However, as the LUC enlarges, the effect of the boundary atoms decreases and the density matrix $\rho^s(\mathbf{R}_n)$ approaches the idempotent density matrix $\rho(\mathbf{R}_n)$.

The above consideration can be interpreted as deduction of the cyclic-cluster model of the infinite crystal when the Hartree–Fock LCAO method (or its semiempirical version with nonlocal exchange) is applied.

The study of the approximate density-matrix properties allowed the implementation of the cyclic-cluster model in the Hartree–Fock LCAO calculations of crystalline systems [95] based on the idempotency relations of the density matrix. The results obtained for cyclic-cluster modeling the rutile TiO_2 structure are discussed in Chap. 9.

The consideration presented allows one to better understand the features of Hartree–Fock self-consistent calculations of the electronic structure of an infinite crystal with a nonlocal exchange potential determined by the offdiagonal elements of the one-electron density matrix. It has been shown that the number of $\mathbf{k}$ -points chosen in the BZ for calculations should be in accord with the size of the interaction range in the coordinate space. In other words, there should be *a correlation between summations over the Bravais lattice in the coordinate space and over the BZ in the reciprocal space*. It was also shown that when the Fock operator (or the Kohn–Sham operator in hybrid DFT methods; see Chap. 7) contains offdiagonal DM elements, the BZ special-point technique should be modified: weighting-function introduction in the direct lattice sums entering the exchange term establishes the necessary balance and removes the artificial divergences. The HF LCAO method is a well-defined starting point for more sophisticated techniques allowing inclusion of the electron correlation. We consider this problem in the next chapter.

Chapter 5

Electron Correlations in Molecules and Crystals

The basic principles of CI, MCSCF, and CC post-HF methods for molecules with regard to the electron correlation effects are discussed. These methods are directly extended to the crystalline solids in the framework of the molecular cluster model. The wavefunction-based post-HF methods for periodic systems are considered. The incremental technique and the Laplace MP2 approach are the most successful approaches to the correlation in solids. The former uses standard molecular codes with clusters of various shapes and sizes to calculate the correlation energy, the latter adopts a formulation of correlation directly in the AO basis. The method of increments allows the estimation of the correlation effects for the crystal ground state and is useful only if the incremental expansion is well convergent, *that is*, if increments up to, say, triples are sufficient, and if increments become rapidly small with increasing distance between the localized orbitals. These conditions were shown to be well met in the case of different solids. The atomic orbital Laplace-transformed MP2 theory also allows evaluating the correlation correction to the bandgap, using the highest-occupied crystal orbitals and lowest-unoccupied crystal orbitals at the point $\mathbf{k}$, where the bandgap is minimum. A local MP2 scheme for periodic systems is now incorporated in the CRYSCOR correlation computer code for nonconducting crystals. In the local MP2 calculations of solids, it is important to exploit point symmetry, in order to confine calculations to an irreducible subset; the saving of computer time and storage can be substantial in a number of cases of importance.

5.1 Electron Correlations in Molecules: Post-Hartree–Fock Methods

5.1.1 What Is the Electron Correlation?

Electrons in molecules and crystals repel each other according to Coulomb's law, with the repulsion energy depending on the interelectron distance as r_{12}^{-1} . This

interaction creates a correlation hole around any electron, *that is*, the probability to find any pair of electrons at the same point of spin-coordinate space is zero. From this point of view, only the Hartree product Ψ_H of molecular or crystalline spin-orbitals $\psi_i(\mathbf{x})$

$$\Psi_H(\mathbf{x}_1, \mathbf{x}_2, \dots, \mathbf{x}_{N_e}) = \psi_1(\mathbf{x}_1)\psi_2(\mathbf{x}_2) \dots \psi_{N_e}(\mathbf{x}_{N_e}) \quad (5.1)$$

is a completely uncorrelated function. The Hartree product (5.1) describes the system of N_e electrons in an independent particle model. This independence means that the probability of simultaneously finding electron 1 at $\mathbf{x}_1$, electron 2 at $\mathbf{x}_2$, *etc.*, ($\mathbf{x}$ means the set of coordinate $\mathbf{r}$ and spin σ variables) is given by

$$\begin{aligned} & |\Psi_H(\mathbf{x}_1, \mathbf{x}_2, \dots, \mathbf{x}_{N_e})|^2 d\mathbf{x}_1 d\mathbf{x}_2 \dots d\mathbf{x}_{N_e} \\ &= |\psi_1(\mathbf{x}_1)|^2 d\mathbf{x}_1 |\psi_2(\mathbf{x}_2)|^2 d\mathbf{x}_2 \dots |\psi_{N_e}(\mathbf{x}_{N_e})|^2 d\mathbf{x}_{N_e} \end{aligned} \quad (5.2)$$

which is the probability of finding electron 1 at $\mathbf{x}_1$ times the probability of finding electron 2 at $\mathbf{x}_2$, *etc.*, *that is*, product of probabilities.

The well-known extended Hückel semiempirical method for molecules and the tight-binding approach to crystals are examples of the models with full absence of electron correlation in the wavefunction. The Hamiltonian in these methods does not include explicitly electron–electron interactions (such a Hamiltonian was defined in Chap. 4 as the one-electron Hamiltonian) so that the total many-electron wavefunction is a simple product (5.1) of the one-electron functions and the total electron energy is a sum of one-electron energies. The semiempirical parameters used in these methods allow one to take the correlation into account at least partly. The difference between the one-electron Hamiltonian and the Hamiltonian of the one-electron approximation (HF method) is the following. The former does not include electron–electron interaction so that the calculation of its eigenvalues and eigenvectors does not require a self-consistent procedure. The Hamiltonian of the one-electron approximation includes explicitly the interelectron interactions; the one-electron approximation is made only in the many-electron wavefunction. The one-electron approximation Hamiltonian depends on the one-electron wavefunctions unknown at the beginning of the calculation (e.g., the Coulomb and exchange parts of the Hamiltonian in the Hartree–Fock method, see Chap. 4), and the self-consistent calculation is required.

As considered in Chap. 4, the Hartree–Fock (SCF) method replaces the instantaneous electron–electron repulsion with the repulsion of each electron with an average electron charge cloud. The HF method assumes that the many-electron wavefunction can be written as one Slater determinant (4.9). The Hartree–Fock method is usually defined as “uncorrelated.” However, the electron motions are no longer completely independent.

For two electrons with different spins, $|\varphi_1(\mathbf{r}_1)\alpha(\sigma_1)\varphi_2(\mathbf{r}_2)\beta(\sigma_2)|$ the probability of finding electron 1 at $\mathbf{r}_1$ and electron 2 at $\mathbf{r}_2$ is

$$\begin{aligned}
P(\mathbf{r}_1, \mathbf{r}_2) d\mathbf{r}_1 d\mathbf{r}_2 &= d\mathbf{r}_1 d\mathbf{r}_2 \int d\sigma_1 \int d\sigma_2 |\Psi|^2 \\
&= \frac{1}{2} [|\varphi_1(\mathbf{r}_1)|^2 |\varphi_2(\mathbf{r}_2)|^2 + |\varphi_1(\mathbf{r}_2)|^2 |\varphi_2(\mathbf{r}_1)|^2] d\mathbf{r}_1 d\mathbf{r}_2 \quad (5.3)
\end{aligned}$$

The electrons are uncorrelated.

For two electrons with the same spin $|\varphi_1(\mathbf{r}_1)\alpha(\sigma_1)\varphi_2(\mathbf{r}_2)\alpha(\sigma_2)|$, the probability of finding electron 1 at $\mathbf{r}_1$ and electron 2 at $\mathbf{r}_2$ is

$$\begin{aligned}
P(\mathbf{r}_1, \mathbf{r}_2) d\mathbf{r}_1 d\mathbf{r}_2 &= \frac{1}{2} (|\varphi_1(\mathbf{r}_1)|^2 |\varphi_2(\mathbf{r}_2)|^2 + |\varphi_1(\mathbf{r}_2)|^2 |\varphi_2(\mathbf{r}_1)|^2 \\
&\quad - [\varphi_1^*(\mathbf{r}_1)\varphi_2(\mathbf{r}_1)\varphi_2^*(\mathbf{r}_2)\varphi_1(\mathbf{r}_2) + \varphi_1(\mathbf{r}_1)\varphi_2^*(\mathbf{r}_1)\varphi_2(\mathbf{r}_2)\varphi_1^*(\mathbf{r}_2)]) d\mathbf{r}_1 d\mathbf{r}_2 \quad (5.4)
\end{aligned}$$

Now, $P(\mathbf{r}_1, \mathbf{r}_2) = 0$. No two electrons with the same spin can be at the same place. This is called the Fermi hole. Thus, *same-spin electrons are correlated in Hartree–Fock; different-spin electrons are not*. Sometimes, it is said that HF methods take into account the so-called spin correlation.

The HF methods are also called by the independent electrons approximation [5], but this independence is restricted by the Pauli principle.

The exact solution of Hartree–Fock–Roothaan equations (4.33) for molecular systems means use of a complete set of basis functions (such a solution corresponds to the Hartree–Fock limit and in practice, can be achieved mainly for the simple molecules).

In modern molecular quantum chemistry, the correlation energy is defined as the difference between the exact energy and the HF energy in a complete basis (Hartree–Fock limit). As one does not know the exact energy, one uses the experimental total energy (the sum of the experimental cohesive energy and free-atom energies) or calculates the exact energy for a given one-electron basis set and defines the basis-set correlation energy as the difference between the exact and HF energies calculated for the same one-electron basis set. In molecular systems, the correlation energy is about 1 eV per electron pair in a bond or lone pair.

The HF method is usually defined as uncorrelated; however, as we see, the electron motions are no longer completely independent. One of the first attempts to include the electron correlation in calculations was made by Fock et al. [96], who suggested the incomplete separation of variables for two-valent atoms.

The key distinction between the Hamiltonian operator and the Fock operator is the following [97]: the former returns the electronic energy for the many-electron system; the latter is really not a single operator but the set of all of the interdependent one-electron operators that are used to find the one-electron functions (molecular or crystalline orbitals) from which the HF wavefunction is constructed as a Slater determinant (4.9). The HF wavefunction corresponds to the lowest possible energy for a single-determinant many-electron wavefunction formed from the chosen basis set.

Including electron correlation in MO theory means an attempt to modify the HF wavefunction to obtain a lower electronic energy when we operate on that modified wavefunction with the Hamiltonian. This is why the name post-Hartree–Fock methods is traditionally used for the methods including the electron-correlation.

As was mentioned in Sect. 4.1.3 in the unrestricted Hartree–Fock approximation (where the coordinate dependence of spin-up and spin-down MOs was allowed to differ), the one-determinant many-electron wavefunction is, in the general case, not an eigenfunction of the total spin operator S^2 . To repair that deficiency, the technique of projection is used [98] so that the resulting wavefunction becomes a sum of several Slater determinants and therefore, partly takes into account electron correlation, *that is*, goes beyond the one-determinant HF approximation. However, the coefficients in the sum of Slater determinants are defined only by the projection procedure, *that is*, the total spin-symmetry requirements introduced for the many-electron wavefunction.

The sum of Slater determinants

$$\Psi = C_0\Psi_{\text{HF}} + C_1\Psi_1 + C_2\Psi_2 + \dots \quad (5.5)$$

is used also in other post-HF approaches: configuration interaction (CI), multiple-configuration SCF (MCSCF), and coupled-cluster (CC) methods applied to include the electron correlation in molecules.

Often, the HF approximation provides an accurate description of the system, and the effects of the inclusion of correlations with CI or MCSCF methods are of secondary importance. In this case, the correlation effects may be considered as a smaller perturbation and as such, treated using the perturbation theory. This is the approach of Möller–Plesset [99] or many-body perturbation theory for the inclusion of correlation effects. In the MP2 approximation, only the second-order many-body perturbations are taken into account.

The above-mentioned quantum-chemical approaches to electron-correlations in molecules (also called wavefunction-based correlation methods) are described in detail in monographs [5, 97] and recent review articles [100, 101] and are implemented in modern computer codes (<http://www.eecs.harvard.edu/~mdw/proj/old/jaguar/release.html>) [33, 102]. The main disadvantage of the wavefunction-based correlation methods is the high scaling of the computational cost with the number of atoms N in a molecule [103], at least when the canonical MOs are used. The scaling of the computational complexity is $O(N^5)$ for the simplest and cheapest method—second-order perturbation theory MP2. For the CC theory, the computational cost scales are $O(N^6)$ and even $O(N^7)$ for the truncated beyond doubles and triples substitutions, respectively. Such a high “scaling wall” [103] restricts the application range of the wavefunction-based correlation methods to molecules of rather modest size. For this reason, the density-functional-based correlation methods (see Chap. 7) remain until now the main way to treat large molecular systems. The main disadvantages of the latter methods are the principal impossibility for systematic

improvements, the underestimation of transition-state energies, and the inability to describe weak interactions (dispersive forces).

The essential progress in the correlation effects inclusion was achieved in the so-called local correlation methods [103, 104] taking into account the short-range nature of the correlation. In these methods, the localized MOs are generated from the occupied canonical MOs using different localization criteria, see Sect. 3.3.1. For the virtual space, the atomic orbital basis is projected out of the occupied MO space.

As compared to the molecules, the wavefunction-based correlation methods for periodic systems are practically reliable only when the molecular cluster model is used. Unfortunately, the well-known problems of the cluster choice and the influence of the dangling bonds on the numerical results restrict the application range of the molecular cluster model to the essentially ionic systems.

The more sophisticated incremental scheme [105–108] maintains the infinite nature of periodic systems, but the correlation effects are calculated incrementally using standard quantum-chemical codes.

Only recently was the MP2 theory applied to the periodic systems based on the local correlation methods and use of Wannier functions [103, 109].

While for the molecules the local correlation methods are already implemented in the MOLPRO code, (<http://www.molpro.net>) the implementation of this approach to the periodic systems is the main goal of the new CRYSCOR project (<http://www.theochem.unito.it/lcc2004/cryscor.pdf>).

In the next sections, we briefly discuss the basic ideas of CI, MCSCF, and CC post-HF methods for molecules as they are directly extended to the crystalline solids in the framework of the molecular cluster model. In more detail, the local correlation and MP2 methods are considered both for the molecules and the periodic systems.

5.1.2 *Configuration Interaction and Multiconfiguration Self-Consistent Field Methods*

Methods designed to account for electron correlation in molecules are divided into two classes: wavefunction (WF)-based methods and density-functional (DF)-based methods. The former use, in one or another way, the HF (noncorrelated) orthonormal MOs and therefore, are also called post-HF (PHF) methods. In the majority of cases, RHF orbitals are used. The latter are based on the density-functional theory (DFT), considered in Chap. 7.

PHF methods can, in turn, be classified as the variational and nonvariational ones. In the former group of methods, the coefficients in linear combination of Slater determinants and in some cases, LCAO coefficients in HF MOs are optimized in the PHF calculations; in the latter, such an optimization is absent. To the former group of PHF methods, one refers different versions of the configuration-interaction (CI) method, the multiconfiguration self-consistent field (MCSCF) method, the variational coupled-cluster (CC) approach, and the rarely used valence bond (VB)

and generalized VB methods. The nonvariational PHF methods include the majority of CC realizations and many-body perturbation theory (MBPT), called in its molecular realization the Möller–Plessett (MP) method. In MP calculations, not only RHF but UHF MOs are also used [102].

In this section, we discuss CI and MCSCF methods; CC and MP approaches are considered in the next sections.

The concept of the electron configuration has sense only when the one-electron functions of space and spin coordinates are used to approximate the corresponding many-electron wavefunction. The latter is called the configuration-state function (CSF) when the basis of spin-adapted many-electron functions is used. The configuration is specified by fixing the occupation numbers of the molecular spin-orbitals (MSO) and the molecular spin state. For the closed-shell singlets (the ground-state configuration), CSF can always be represented as a single determinant and transforms over identity representation of the molecular point-symmetry group. As the degeneracy of the molecular one-electron states is defined by the dimensions of the irreps of the corresponding point-symmetry group, the closed-shell configuration occupation numbers are zero or twice these dimensions (α and β electron-spin projections are allowed). In the majority of open-shell systems (excited-states configurations or ground states of radicals), proper CSFs can only be represented by a combination of two or more Slater determinants. Let the Hartree–Fock–Roothaan (MO LCAO) equations (4.33) be solved and the Slater determinant $\Phi_0 = \Psi_{\text{HF}} = |\psi_1, \psi_2, \dots, \psi_N|$ in (5.5) is obtained. Solving MO LCAO equations will give $M > N$ orthonormal MSOs (M is the total number of AOs used in the calculation, and N is the number of electrons). For the ground state, the N energetically lowest MSOs are occupied, which results in the HF determinant. To construct Slater determinants for excited states, we may also use energetically higher orbitals, being vacant in the HF solution. It should be added that all MSOs (both those that for the ground state are occupied and those that are empty) are orthonormal as the eigenfunctions to the same Hartree–Fock operator. This represents an important simplification in the calculations.

In the full CI (FCI) method (precise with respect to the basis chosen), M HF MOs φ_i ($i = 1, 2, \dots, M$) generate $N_{\text{CI}} = C_M^{\frac{1}{2}N + M_S} C_M^{\frac{1}{2}N - M_S}$ determinants for the system with N electrons and fixed total spin projection M_S .

Let us rewrite the many-determinant wavefunction (5.5) in the form

$$\Phi = \sum_{I=0}^{N_{\text{CI}}-1} C_I \Phi_I \quad (5.6)$$

where index I numbers different configurations. The HF approximation corresponds to $I = 0$ and $C_0 = 1$ and $C_I = 0$ for $I > 0$ in (5.6).

In the FCI method, all MSOs are usually supposed to be fixed as the solutions of HF MO LCAO equations, but the parameters CI are varied in the expression

$$L = \langle \Phi | \hat{H}_e | \Phi \rangle - \lambda [\langle \Phi | \Phi \rangle - 1] \quad (5.7)$$

We find [8]

$$\begin{aligned}
 & \frac{\partial}{\partial C_K^*} \left[\langle \sum_I C_I \Phi_I | \hat{H}_e | \sum_J C_J \Phi_J \rangle - \lambda \langle \sum_I C_I \Phi_I | \sum_J C_J \Phi_J \rangle \right] \\
 &= \frac{\partial}{\partial C_K^*} \sum_{I,J} C_I^* C_J \left[\langle \Phi_I | \hat{H}_e | \Phi_J \rangle - \lambda \langle \Phi_I | \Phi_J \rangle \right] \\
 &= \sum_J C_J \left[\langle \Phi_K | \hat{H}_e | \Phi_J \rangle - \lambda \langle \Phi_K | \Phi_J \rangle \right] = 0
 \end{aligned} \tag{5.8}$$

This gives the matrix eigenvalue problem

$$HC = \lambda SC \tag{5.9}$$

where

$$H_{KJ} = \langle \Phi_K | \hat{H}_e | \Phi_J \rangle, \quad S_{KJ} = \langle \Phi_K | \Phi_J \rangle \tag{5.10}$$

and the eigenvalue in (5.9) is equal to

$$\lambda = \frac{\langle \Phi | \hat{H}_e | \Phi \rangle}{\langle \Phi | \Phi \rangle} \tag{5.11}$$

The Hamiltonian operator $\hat{H} = \hat{h} + \hat{g}$ consists of the single-electron $\hat{h} = \sum_{i=1}^N \hat{h}(\mathbf{r}_i)$

and two-electron $\hat{g} = \frac{1}{2} \sum_{i \neq j=1}^N \frac{1}{|\mathbf{r}_i - \mathbf{r}_j|}$ parts. Calculating for operators $\hat{h}$ and $\hat{g}$ the matrix elements $\langle \Phi | \hat{h} | \Phi \rangle$, $\langle \Phi | \hat{g} | \Phi \rangle$ and taking into account the orthonormality of MSOs, it can be shown [8] that:

1. Different configurations are orthonormal.
2. For any single-electron operator $\hat{h}$, there will be nonvanishing matrix elements only between configurations that differ at most in one MSO.
3. For any two-electron operator $\hat{g}$, there will be nonvanishing matrix elements only between configurations that differ at most in two MSOs. The MOs φ_i are solutions to the HF equations

$$\hat{F} \varphi_i = \epsilon_i \varphi_i \tag{5.12}$$

where

$$\hat{F} = \hat{h} + \sum_{j=1}^N \left(\hat{J}_j - \hat{K}_j \right) \tag{5.13}$$

The j summation in (5.13) runs over all those orbitals that for the ground-state configuration Φ_0 are occupied. The Coulomb $\hat{J}_j$ and exchange $\hat{K}_j$ operators were defined in (4.16) and (4.17).

Let now the matrix elements $\langle \Phi_J | \hat{H}_e | \Phi_I \rangle$ be calculated, where $\Phi_I = \Phi_0$ and $\Phi_J = \Phi_n^\nu$ (in the Φ_n^ν configuration, one electron has been excited from the n th occupied spin-orbital to the ν th empty spin-orbital). It can be shown [8] that both overlap and Hamiltonian matrix elements vanish between the ground-state configuration Φ_0 and any single-excited one. Having determined all the relevant matrix elements of (5.9), one may obtain the wavefunction (5.6) as well as the corresponding total electron energy of the FCI method. Notice that in contrast to the HF calculations, the FCI calculations do not require any self-consistency with respect to MOs. Diagonalization of the N -electron Hamiltonian in the basis of Slater determinants gives us energies and WFs of the ground and excited states of the system. It is pertinent to note that for the FCI method, the choice of MO basis is not important because any unitary transformation of the MO basis induces unitary transformation of the determinant basis.

The FCI method is the most general of several theories for treating electron correlations. As a variational method, it provides upper bounds for the correlation energy. By definition, the FCI calculation means that all N_{CI} configurations (possible for a given number of electrons N and M AO basis functions) are included in the sum (5.6). FCI calculations can be practically realized only for small molecules and small basis sets as the number of possible configurations drastically increases with increasing number of atoms in a molecule and large-scale CI calculations become very expensive.

As an example, the CH_4 molecule with 10 electrons can be taken [5]. Using a minimal basis set of 9 AOs ($1s$, $2s$, $2p$ for the C atom and $1s$ for each of four H atoms), one can construct $N_{\text{CI}} = 43,758$ Slater determinants (configurations). When the tetrahedral point-symmetry restrictions are taken into account, this number considerably reduces ($N_{\text{CI}} = 5,292$ for singlet states). Enlarging the basis set to 35 functions (double-zeta plus polarization basis, see Chap. 8) increases the number of singlets to 2×10^{10} . When larger molecules are considered and larger basis sets are used, the restriction of the chosen configurations is required. There are several ways of achieving this restriction:

1. Develop some procedure for selection of the most important configurations. In its most general form, this method is called GenCI. Frequently used methods are CIS, CID, CISD, CISDT, *etc.*, where 1-electron, 2-electron, 1+2-electron, and 1+2+3-electron excitations of electrons from occupied HF states to virtual ones are taken into account. These methods can be called restricted CI (RCI) methods. In some computer codes for molecular calculations, automatic selection of the most important configurations is performed (<http://www.emsl.pnl.gov/docs/nwchem/>).
2. Subdivide one-electron MOs into several groups. The most primitive subdivision is in three groups: inactive MOs, active MOs, and virtual MOs. Inactive MOs have occupancy 2 in all determinants in CI expansion, virtual MOs have occupancy 0 in all determinants in CI expansion, and occupancies of active MOs are between 0 and 2. It is supposed that in CI wavefunction, only excitations within active MOs are taken into account.

3. Combination of 1 and 2, that is, subdivision of MOs into groups and use of RCI in the active space.

If RCI expansions are used or orbitals are subdivided into inactive and active groups, or both, then variation of the orbitals themselves may lead to an essential energy decrease (in contrast to the FCI method where it does not happen). Such combined methods that require both optimization of CI coefficients and LCAO coefficients in MOs are called MCSCF methods. Compared with the CI method, the calculation of the various expansion coefficients is significantly more complicated, and as for the Hartree–Fock–Roothaan approximation, one has to obtain these using an iterative approach, *that is*, the solution has to be self-consistent (this gives the label SCF).

One of the most popular methods of MCSCF class is the complete active space SCF (CASSCF) method by Roos [110] where FCI is performed in active space and optimization of MOs is also done. Note that active–active orbital rotations are irrelevant in the framework of this method.

The most popular version of the RCI method application is to restrict by only single- and double-excited configurations (CISD method). It is well known that the CI single (CIS) method finds no use for ground states as the ground-state HF energy is unaffected by inclusion of single excitations (Brillouin theorem [97]). In the CISD method, the singly excited determinants mix with doubles and thus can have some influence on the lowest eigenvalue [97]. What about triple excitations? While there are no nonzero matrix elements between the ground state and triply excited states, the triplets do mix with the doubles and can through them influence the lowest-energy eigenvalue (CISDT method). So, here is some motivation for including them. On the other hand, there are a lot of triples, making their inclusion difficult in a practical sense. As a result, triples and higher-level excitations are usually not accounted for in the RCI methods so that the CISD approximation dominates in CI calculations. The scaling for CISD with respect to system size, in the large basis limit, is on the order of N^6 . It poses a limit on the sizes of systems that can be practically addressed. Fortunately, the symmetry restrictions allow significant reduction in the computational effort. Similarly, the core orbitals can be frozen in the generation of the excited state.

5.1.3 Coupled-Cluster Methods

The CC method [111] is one of the mathematically elegant techniques for estimating the electron correlation [97, 112]. In this method, the FCI wavefunction is represented as

$$\Psi_{\text{CC}} = \exp(\hat{T})\Psi_{\text{HF}} \quad (5.14)$$

The cluster operator $\hat{T}$ is defined in terms of standard creation–annihilation operators as

$$\hat{T} = \sum_j^{\leq N} \sum_i^{>N} t_j^i a_i^\dagger a_j + \sum_{j_1 < j_2}^{\leq N} \sum_{i_1 < i_2}^{>N} t_{j_1 j_2}^{i_1 i_2} a_{i_1}^\dagger a_{i_2}^\dagger a_{j_1} a_{j_2} + \dots \quad (5.15)$$

Coefficients t in the last expansion are called the CC amplitudes, and they can be defined either variationally or by solving a system of linear equations. The total number of items in (5.15) equals the number of electrons N because no more than N excitations are possible. In most computer codes, the nonvariational CC method is implemented since the variational one is technically very complicated. Formally operating on the Ψ_{HF} with $(1 + \hat{T})$ gives, in essence, the FCI wavefunction. However, the advantage of the CC representation (5.14) lies in the consequences associated with truncation of $\hat{T}$ [97]. When, in (5.15), only single or double excitations are involved, the method is called CCS or CCD, respectively, when single and double excitations—then CCSD, *etc.* Let us consider as an example the CCD approximation when $\hat{T} = \hat{T}_2$ and the expansion (5.15) has the form

$$\Psi_{\text{CCD}} = \exp(\hat{T}_2) \Psi_{\text{HF}} = \left(1 + \hat{T}_2 + \frac{\hat{T}_2^2}{2!} + \frac{\hat{T}_2^3}{3!} + \dots \right) \Psi_{\text{HF}} \quad (5.16)$$

Note that the first two terms in parentheses of (5.16) define the CID method. However, the remaining terms involve products of excitation operators. Each application of $\hat{T}_2$ generates double excitations, so the product of two applications generates quadruple excitations. Similarly, the cube of $\hat{T}_2$ generates hextuple substitutions, *etc.* Such high-level excitations cannot be practically included in CI calculations (in this sense, the RCI method is called nonsize consistent).

The computational problem of the CC method is determination of the cluster amplitudes t for all of the operators included in the particular approximation. In the standard implementation, this task follows the usual procedure of left-multiplying the Schrodinger equation by trial wavefunctions expressed as determinants of the HF orbitals. This generates a set of coupled, nonlinear equations in the amplitudes that must be solved, usually by some iterative technique. With the amplitudes in hand, the coupled-cluster energy is computed as

$$E_{\text{CC}} = \langle \Psi_{\text{HF}} | \hat{H} | \exp(\hat{T}) \Psi_{\text{HF}} \rangle \quad (5.17)$$

In practice, the cost of including single excitations $\hat{T}_1$ in addition to doubles is worth the increase in accuracy, and this defines the CCSD model. The scaling behavior of CCSD is on the order of N^6 . Inclusion of connected triple excitations (i.e., those arising with their own unique amplitudes from $\hat{T}_3$, not the disconnected triples arising as products of $\hat{T}_1$ and $\hat{T}_2$) defines CCSDT, but this is very computationally costly scaling as N^8 and making it intractable for all but the smallest of molecules. Various approaches to estimating the effects of the connected triples using perturbation theory have been proposed (each with its own acronym). Of these, the most robust, and thus most commonly used, is that in the so-called CCSD(T) method, which

also includes a singles/triples coupling term [113]. The (T) approach, in general, slightly overestimates the triples correction and does so by an amount about equal to the ignored quadruples, *that is*, there is a favorable cancelation of errors [114]. This makes the CCSD(T) model extremely effective in most instances. Analytic gradients [115] and second derivatives [116] are available for CCSD and CCSD(T), which further increases the utility of these methods. Note, however, that truncated coupled-cluster theory is not variational.

5.1.4 Many-Electron Perturbation Theory

We follow in this subsection the many-electron perturbation theory description given in [8]. Often, the Hartree–Fock approximation provides an accurate description of the system, and the effects of the inclusion of correlations, *for example*, with the CI or MCSCF methods, may be considered as important but small corrections. Accordingly, the correlation effects may be considered as a small perturbation and as such, treated using the perturbation theory. This is the approach of [117] for the inclusion of correlation effects.

For the sake of simplification, we shall here consider the ground state but mention that the method in principle can be applied for any state, *that is*, also for an excited state.

Our starting point is the Hartree–Fock equations (4.13) where the HF operator $\hat{F}$, (4.14) is a single-electron operator, being a sum of the one-electron operator $\hat{h}$, (4.8), local Coulomb $\hat{J}$, (4.16) and nonlocal exchange $\hat{K}$, (4.17) operators.

Solving HF equations (4.13) gives not only the N occupied orbitals but—in principle—a complete set of M (total number of AO basis functions) orbitals, since $\hat{F}$ is a Hermitian operator.

The operator $\hat{F}$ is a single-electron operator, which we formally wrote as $\hat{F}(i)$, where i numbers electrons. We define now first the N -electron operator

$$\hat{G}' = \sum_{i=1}^N \hat{F}(i) \quad (5.18)$$

This is also a Hermitian operator, and the N -electron Slater determinants

$$|\psi_{i_1}, \psi_{i_2}, \dots, \psi_{i_N}| \quad (5.19)$$

define a complete set of eigenfunctions with

$$\hat{G}'|\psi_{i_1}, \psi_{i_2}, \dots, \psi_{i_N}| = (\varepsilon_{i_1} + \varepsilon_{i_2} + \dots + \varepsilon_{i_N})|\psi_{i_1}, \psi_{i_2}, \dots, \psi_{i_N}| \quad (5.20)$$

In particular, for the ground state we have

$$\hat{G}'|\psi_1, \psi_2, \dots, \psi_N| = \left[\sum_{i=1}^N \varepsilon_i \right] |\psi_1, \psi_2, \dots, \psi_N| \quad (5.21)$$

It follows from (4.38) that

$$\sum_{i=1}^N \varepsilon_i = E_{\text{HF}} + \frac{1}{2} \sum_{i,j=1}^N \left[\langle \psi_i \psi_j | \frac{1}{|\mathbf{r}_1 - \mathbf{r}_2|} | \psi_i \psi_j \rangle - \langle \psi_j \psi_i | \frac{1}{|\mathbf{r}_1 - \mathbf{r}_2|} | \psi_i \psi_j \rangle \right] = E_{\text{HF}} + E' \quad (5.22)$$

where

$$E' = \frac{1}{2} \sum_{i,j=1}^N \left[\langle \psi_i \psi_j | \frac{1}{|\mathbf{r}_1 - \mathbf{r}_2|} | \psi_i \psi_j \rangle - \langle \psi_j \psi_i | \frac{1}{|\mathbf{r}_1 - \mathbf{r}_2|} | \psi_i \psi_j \rangle \right] \quad (5.23)$$

Since the total electronic energy from the Hartree–Fock approximation is the starting point in the perturbation calculation, we see from (5.22) that it is convenient to consider the operator

$$\hat{G} = \hat{G}' - E' \quad (5.24)$$

Operator $\hat{G}$ has the same eigenfunctions as $\hat{G}'$, but the eigenvalues have been shifted by E' . The precise form of $\hat{G}$ is

$$\hat{G} = \sum_{i=1}^N \hat{F}(i) - E' = \sum_{i=1}^N \hat{h}(i) + \sum_{i,j=1}^N \left[\hat{J}_j(i) - \hat{K}_j(i) \right] - E' \quad (5.25)$$

This can be compared with the true N -electron Hamilton operator,

$$\hat{H}_e = \sum_{i=1}^N \hat{h}(i) + \frac{1}{2} \sum_{i \neq j} \frac{1}{|\mathbf{r}_i - \mathbf{r}_j|} \quad (5.26)$$

In order to apply perturbation theory, we write

$$\hat{H}_e = \hat{G} + \Delta \hat{H} \quad (5.27)$$

with

$$\Delta \hat{H} = \frac{1}{2} \sum_{i \neq j} \frac{1}{|\mathbf{r}_i - \mathbf{r}_j|} - \sum_{i,j=1}^N \left[\hat{J}_j(i) - \hat{K}_j(i) \right] + E' \quad (5.28)$$

First-order perturbation theory gives that the ground-state energy changes by

$$\langle \Phi_0 | \Delta \hat{H} | \Phi_0 \rangle \quad (5.29)$$

By using the precise form of the operators in (5.28), one may now show that this term vanishes. The proof of this is very similar to the one showing that the Hamiltonian matrix elements between the ground state and any single-excited configuration vanish [8]. First, the second-order term is nonvanishing. This term is

$$\sum_{i,j} \sum_{\alpha,\beta} \frac{\langle \Phi_0 | \Delta \hat{H} | \Phi_{i,j}^{\alpha,\beta} \rangle \langle \Phi_{i,j}^{\alpha,\beta} | \Delta \hat{H} | \Phi_0 \rangle}{E_0 - E_{i,j}^{\alpha,\beta}} \quad (5.30)$$

where we have used the fact that only those configurations $\Phi_{i,j}^{\alpha,\beta}$ where exactly two electrons have been excited from the ground state Φ_0 have nonvanishing matrix elements in the denominator. To prove this, one uses the fact that $\Delta \hat{H}$ consists of two-electron operators and that there will be nonvanishing elements only when the two determinants differ by at most two orbitals. It can also be proved that there is no contribution from single-excited configurations. Furthermore,

$$E_0 = \sum_{i=1}^N \epsilon_i - E' = E_{\text{HF}} \quad (5.31)$$

and

$$E_{i,j}^{\alpha,\beta} = E_{\text{HF}} + \epsilon_\alpha + \epsilon_\beta - \epsilon_i - \epsilon_j \quad (5.32)$$

are the eigenvalues of G' . The most important aspect is now that the denominator in (5.30) equals

$$-\epsilon_\alpha - \epsilon_\beta + \epsilon_i + \epsilon_j \quad (5.33)$$

due to (5.32). The two first energies are energies of orbitals that for the ground state are vacant, whereas the last two are those of occupied orbitals. This means that the denominator is small (and, hence, the correlation effects are large) when there is a small energy difference between occupied and unoccupied orbitals. This partly explains the results for the H + H system where the correlation is important for large interatomic distances, when the energies of the occupied and unoccupied orbitals approach each other. The result tells us also that, *for example*, for compounds containing transition-metal atoms, where there are many (empty and occupied) *d* orbitals close to each other, we will expect that correlation effects are important or, alternatively, that the Hartree–Fock approximation (i.e., the single-Slater-determinant approximation) is not a very good one. Turning to the cyclic model of a crystalline solid, we conclude that the smaller the bandgap, the larger the correlation effects on the ground-state energy.

The higher-order terms to the perturbation series can also be calculated. These will become increasingly complex, but already second-order MP2 perturbation theory provides a very important improvement over the pure Hartree–Fock approximation, and in very many cases, results from this method are highly accurate. The higher-order calculations are given the labels MP3, MP4. We do not discuss here many numerical results for the ground state of molecular systems obtained

in CI, MCSCF, CC, or perturbation theory calculations; rather, we refer the reader to monographs [5, 8, 97]. Meanwhile, it is clear that direct extension of CI or CC methods to the molecular cluster models of periodic systems is a difficult task. The molecular cluster reasonably models the periodic system when it is chosen sufficiently large to suppress the dangling bonds influence. Even for ionic crystals, such a cluster can consist of up to 50–100 atoms. The one possibility of the calculation efforts decreasing is connected with the use of localized MOs in the Slater determinants. The local electron correlation methods are considered in the next subsection.

5.1.5 Local Electron Correlation Methods

In the wavefunction-based improvements upon mean-field HF method to account for electron correlation (CI, CC, MP), the demands on the computational resources (CPU time, memory, or disk space) exhibit a strong dependence on the system size. Let the system consist of N atoms. If we assume a given basis set, the cost of MP2 calculations scales between N^3 and N^5 (asymptotic limit)[118]. Higher correlation methods CCSD and CCSD(T) scale as N^6 and N^7 , respectively. The latter means that doubling the size of the molecular system increases the computational costs by a factor of 64 and 128! This high scaling behavior restricts the application range for these accurate and reliable methods to only small molecules, a traditional dilemma in quantum chemistry for a long time (especially, since density-functional theory became available).

Local electron correlation methods are *ab initio* wavefunction-based electronic-structure methods that exploit the short-range nature of dynamic correlation effects and in this way allow linear scaling $O(N)$ in the electron correlation calculations [119, 120, 122–126] to be attained. $O(N)$ methods are applied to the treatment of extended molecular systems at a very high level of accuracy and reliability as CPU time, memory, and disk requirements scale linearly with increasing molecular size N .

Linear-scaling electron correlation methods were developed by (1) combining the Pulay–Saebo local correlation variant [127] with integral-direct techniques [122] and consequently exploiting the spatial locality of the electron correlation effect; and (2) Laplace-transform techniques suggested in [128] and applied in [120].

In a first step, a linear-scaling local MP2 (LMP2) algorithm was implemented [120, 122, 123]. With this algorithm, MP2 calculations on spatially extended molecular systems including more than 200 atoms and 2,000 basis functions can easily be performed on a current low-cost Pentium PC. The linear-scaling approach was also developed for high-level correlation methods, *that is*, linear scaling and local CCSD with (T) correction [124, 125, 133, 134]. In particular, for the CCSD(T) method, reductions in required CPU time were obtained by more than a factor of 1,000 compared to the conventional (T) method.

The chemical systems well beyond 1,000 basis functions, 100 atoms, and some hundred correlated electrons are now within reach of the local electron correlation methods. It is clear that these methods still are considerably more expensive than modern, linear-scaling DFT algorithms (see Chap. 7), but this now is just due to a higher prefactor and no longer due to less favorable scaling behavior. Thus, the long-standing scaling problem of *ab initio* electronic-structure theory clearly is defeated. On the other hand, local correlation methods combine all the well-known advantages of wavefunction-based methods over DFT, like reliability and possibilities for systematic improvements.

At first, all these methods were developed for closed-shell systems only. Later research in this area was directed toward local methods for open-shell systems and excited states, local triples corrections beyond (T) (triples included in coupled-cluster iterations), [129], local energy gradients for geometry optimizations of large molecules [130], and combination of the local correlation method with explicitly correlated wavefunctions. It is evident from the discussion that these local $O(N)$ methods open the applications of coupled-cluster theory to entirely new classes of molecules, which were far out of scope for such an accurate treatment before. Possible applications lie, for example, in the determination of the thermochemistry of reactions involving large closed-shell (or singlet biradialic) organic molecules including the computation of accurate barrier heights (which is an area where DFT often fails badly). Furthermore, once local MP2 NMR shifts become available, NMR spectra of extended organic molecules could reliably be predicted, which might be helpful in the determination of the structure of such molecules.

Another potential application field are intermolecular complexes and clusters [131]. Here, the local correlation method has some conceptual advantages, insofar that it eliminates the notorious basis-set superposition error (BSSE) [132]. This allows for the BSSE-free calculation of interaction energies structures of large molecular clusters (i.e., involving many monomers) without the expensive counterpoise correction that is required in conjunction with canonical methods. There are many more application areas one could think of.

One of the most impressive applications of the local correlation methods is their extension to the periodic systems. Having in mind to discuss this extension on the MP2 level in the next section, we restrict the discussion here to the consideration of local MP2 methods for molecular systems with closed shells, referring the reader to the papers discussing local CC methods [119, 124, 125, 133, 134].

In the local MP2 method [122], the occupied canonical MOs of the preceding HF calculation are localized using the Pipek–Mezey [35] localization procedure and keeping the localized orbitals orthonormal. Even though the localization is formally an $O(N^3)$ step, the localization time is negligible for all the local MP2 calculations.

The use of local orbital bases opens the way for two distinct approximations. First, for the correlation of each electron pair ij , an individual subset (domain) of the virtual orbitals that is independent of the molecular size can be selected. This reduces the scaling of the number of configuration-state functions (CSFs) and corresponding amplitudes from $O(N^4)$ to $O(N^2)$. Secondly, a hierarchical treatment of different electron pairs depending on the minimum distance R of

the two correlated localized occupied MOs (LMOs) i and j can be devised. In implementation [122], a subset of atoms is assigned to each LMO according to the procedure of [135]. The pairs (ij) are then classified according to the minimum distance between any atoms in the two different subsets. *Strong pairs* ($R \leq 1$ Bohr) are treated at the highest level, *for example*, local CCSD. These involve pairs of local orbitals that share at least one atom and typically account for more than 90% of the correlation energy. *Weak pairs* ($1 < R \leq 8$ Bohr) and *distant pairs* ($8 < R \leq 15$ Bohr) are (optionally) treated by local MP2, while *very distant pairs* ($R > 15$ Bohr) can be entirely neglected (in [122], strong and weak pairs are both treated by LMP2). For the distant pairs, the required two-electron integrals can be obtained using multipole approximations [136] leading to substantial savings. The numbers of strong, weak, and distant pairs scale only linearly with molecular size N , whereas the number of very distant pairs scales quadratically with N . The neglect of very distant pairs leads to an overall linear dependence of the number of CSFs and of the corresponding transformed integrals. The multipole treatment of distant pairs further reduces the number of integrals that must be constructed via the four-index integral transformation; this fact can be exploited to devise an integral transformation algorithm for which all computational resources (CPU, memory, and disk) scale only linearly with N [122].

In the basis $\{\chi_\mu\}$ with overlap matrix $S_{\mu\nu} = \langle \chi_\mu | \chi_\nu \rangle$, the localized occupied orbitals $|\phi_i\rangle$ are represented by a coefficient matrix L

$$|\phi_i\rangle = \sum_{\mu} |\chi_\mu\rangle L_{\mu i} \quad (5.34)$$

The virtual space is spanned by a set of nonorthogonal functions $\{\tilde{\phi}_r\}$ that are obtained directly from the AOs $\{\chi_\mu\}$ by projecting out the occupied space, *that is*,

$$|\tilde{\phi}_r\rangle = \left(1 - \sum_{i=1}^m |\phi_i\rangle \langle \phi_i|\right) |\chi_\mu\rangle = \sum_{\mu} |\chi_\mu\rangle P_{\mu\nu} \quad (5.35)$$

where the projection matrix is defined as

$$P = I - LL^\dagger S \quad (5.36)$$

Here, indices $i, j, \dots$, are used for the occupied LMOs, $r, s, \dots$, for projected AOs and μ, ν, ρ, σ for AOs. The functions in the projected basis are capped by a tilde.

To each LMO $|\phi_i\rangle$, a subset $[i]$ (orbital domain) of the projected AOs $|\tilde{\phi}_r\rangle$ is assigned. The orbital domains are selected in [122] as described by Boughton–Pulay [135] using a threshold of 0.02 but in addition, discarding centers with a Mulliken gross charge below 0.01 (0.03 for H atoms). The electron pairs (ij) were classified as strong, weak, or distant, and very distant pairs ($R > 15$ Bohr) were neglected. The correlation space for the strong and weak electron pairs (ij) was spanned by pair domains $[ij] = [i] \cup [j]$, which are the union of the two related orbital domains.

Distant pairs were treated by a multipole approximation, as described in [136]. This requires the use of asymmetric pair domains $r \in [i]$, $s \in [j]$ for this class of configurations, *that is*, long-range ionic excitations are neglected. The error of this approximation is negligible if the cutoff distance is chosen to be $R > 8$ Bohr. The linear dependencies are removed for each individual pair domain separately, as described in detail in [119].

In the local basis, the first-order wavefunction takes the form

$$|\Psi^{(1)}\rangle = \frac{1}{2} \sum_{ij \in P} \sum_{rs \in [ij]} \tilde{T}_{rs}^{ij} |\Phi_{ij}^{rs}\rangle \text{ with } \tilde{T}_{rs}^{ij} = \tilde{T}_{sr}^{ji} \quad (5.37)$$

where P represents the pair list and it is implicitly assumed that the pair domains $[ij]$ are defined as described above. Note that the number of projected functions $r, s \in [ij]$ for a given pair (ij) is independent of the molecular size. Therefore, the individual amplitude matrices $\tilde{T}_{rs}^{ij}$ are very compact, and their sizes are independent of the molecular size. The total number of amplitudes $\tilde{T}_{rs}^{ij}$ depends linearly on the molecular size, and it is assumed that they can be stored in high-speed memory.

Since the local orbital basis does not diagonalize the zeroth-order HF Hamiltonian, an iterative procedure is required to determine the amplitudes $\tilde{T}^{ij}$. By minimizing the Hylleraas functional, one obtains the linear equations [121]

$$\tilde{R}^{ij} = \tilde{K}^{ij} + \tilde{F} \tilde{T}^{ij} \tilde{S} + \tilde{S} \tilde{T}^{ij} \tilde{F} - \sum_k \tilde{S} [F_{ik} \tilde{T}^{kj} + F_{kj} \tilde{T}^{ik}] \tilde{S} \quad (5.38)$$

For the desired solution, the residuals $(\tilde{R}^{ij})_{rs}$ must vanish for $r, s \in [ij]$. The quantities $\tilde{S}$ and $\tilde{F}$ are the overlap and Fock matrices in the projected basis, respectively, and the exchange matrices $(\tilde{K}^{ij})_{rs} = (ri|sj)$ represent a small subset of the transformed two-electron integrals. For a given pair (ij) , only the local blocks $(\tilde{K}^{ij})_{rs}$, $\tilde{F}_{rs}$, and $\tilde{T}_{rs}$ for $r, s \in [ij]$ are needed in the first three terms, while for the overlap matrices in the sum, only the blocks connecting the domain $[ij]$ with $[ik]$ or $[jk]$ are required. The sizes of all these matrix blocks are independent of the molecular size. Taking further into account that for a given pair (ij) the number of terms k in the summation becomes asymptotically independent of the molecular size if very distant pairs are neglected, it follows that the computational effort scales linearly with molecular size. Further savings are possible by skipping terms with coupling matrix elements F_{ik} or F_{kj} falling below a certain threshold, which can be progressively reduced as the iteration proceeds. In the calculations [122], the initial threshold was set to 10^{-2} and reduced in each iteration by a constant factor until the final value of 10^{-5} was reached. This threshold yields the energy to an accuracy better than 10^{-7} Hartree. This screening reduces the iteration time but is not essential for achieving linear scaling. There are two possible algorithms to compute the terms in the sum. In the first algorithm (I), the matrix multiplications $\tilde{S} \times \tilde{T}^{kj} \times \tilde{S}$ are performed inside the summation, which seems wasteful at first glance but has the advantage that all matrix multiplications are over small local blocks only.

Alternatively, in the second algorithm (II), the matrix multiplications are performed outside the summation, but then the accumulated matrix in the square brackets has a much larger dimension, which is the union of all pair domains having either the orbital i or j in common. If very distant pairs are neglected, these united-pair domains (UP2) also become independent of molecular size, and therefore, algorithm II scales linearly with molecular size as well. A comparison of the measured CPU times for both algorithms for linear chains of polyglycine peptides as a function of the number of monomers [122] shows that both algorithms closely approach linear scaling. It was found that Algorithm I has a significantly lower prefactor than Algorithm II and has therefore been chosen as the default in the MOLPRO program (<http://www.molpro.net>). Note that both algorithms would lead to $O(N^3)$ scaling if the very distant pairs were not neglected. Typically, 5–7 iterations are needed to converge the energy to better than 10^{-7} Hartree; the number of iterations has been found to be essentially independent of the molecular size.

The potential bottleneck is the following: the overlap and Fock matrices are stored in memory as full $M \times M$ matrices, where M is the number of AOs. The subblocks needed for a given matrix multiplication are extracted on the fly from these matrices. Full square matrices are also needed for computing and storing the projected orbitals. Thus, the memory requirement formally scales with $O(M^2)$, but since only very few full matrices are needed, the prefactor is so small that this causes no bottleneck in practice for up to 2,000–3,000 basis functions. In principle, this bottleneck could be avoided by storing for each pair only the local subblocks needed. This would lead to strict linear scaling of the memory (or disk) requirements.

Once the amplitudes have converged, the second-order correlation energy is obtained by tracing the amplitudes with the exchange matrices, *that is*,

$$E_2 = \sum_{ij \in P} \sum_{rs \in [ij]} (2\tilde{T}_{rs}^{ij} - \tilde{T}_{sr}^{ij}) \tilde{K}_{rs}^{ij} \quad (5.39)$$

The overall cost to solve the linear equations (5.38) and to compute the second-order energy (5.39) depends linearly on the molecular size and does not constitute any computational or storage bottleneck, once the necessary quantities are available. As in the canonical case, the computational effort of a local MP2 calculation is entirely dominated by the integral transformation required to construct the exchange matrices $\tilde{K}^{ij}$. The linear-scaling integral transformation is considered in detail in [122, 123].

The optimization of atomic structures requires the availability of analytic energy gradients. In the LMP2 method, the bottleneck is the calculation of the 4-index electron-repulsion integrals (ERIs) and their transformation from the atomic orbitals into the local orbital basis. The computational effort for this step scales with the fourth power of the basis-set size (for fixed molecular size), and therefore, the cost quickly increases with basis-set quality. The same is true for the computation of LMP2 (or MP2) energy gradients, which requires a reverse transformation of the amplitudes from the molecular orbitals into the atomic orbital basis. It has been demonstrated for LMP2 [137] and LCCSD [138] that the computational effort for

ERI evaluation and transformation can be reduced by 1–2 orders of magnitude using density-fitting (DF) methods. In the DF approach, the one-electron charge densities in the ERIs, which are binary products of orbitals, are approximated by linear expansions in an auxiliary basis set. This leads to a decomposition of the 4-index ERIs in terms of 2- and 3-index ERIs, and the $O(M^4)$ AO dependence of the computational cost is reduced to $O(M^3)$. Linear scaling of the computational cost with molecular size in the context of DF can be achieved by employing the concept of locality also for the fitting functions. The key here is the use of local fitting domains, as discussed in [137, 138]. Furthermore, local-density fitting can be used to speed up the calculation of the exchange part to the Fock matrix in Hartree–Fock calculations [137]. The fitting errors introduced by the DF approximation are systematic and substantially smaller than any other typical errors of the calculation (like basis-set truncation or the error due to the local approximation), provided that a suitable auxiliary basis set is employed. Energy gradients for canonical DF-MP2 on top of an ordinary Hartree–Fock (HF) reference function, *that is*, without invoking the DF approximation already at the HF level, were first implemented in [139]. An efficient method to compute analytical energy derivatives for the local MP2 approach was presented in [130] where the advantages of the local and density-fitting approximations in the calculation of analytic energy gradients were combined. All 4-index integrals and their derivatives were replaced by products of 2-index and 3-index quantities, which can be manipulated very efficiently. Moreover, the expensive backtransformation of the effective second-order density matrix into the AO basis was avoided. As a consequence, the method has a much lower prefactor than conventional MP2 gradient programs, and the effort scales only cubically with the basis-set size for a given molecule.

Many applications of local MP2 and local CCSD methods to molecular systems can be found in [123–125, 130, 133, 140].

Another linear-scaling MP2 algorithm was proposed in [120] that is based on the atomic orbitals Laplace-transform (LT) MP2 method [128]. In this method, the energy denominators (5.32) in (5.30) are eliminated by Laplace-transformation, which paves the way to express the MP2 energy directly in the AO basis. The price to pay is the additional Laplace integration, which is carried out by quadrature over a few (8–10) points. For each of the quadrature points, an integral transformation has to be performed, but the transformation matrices are much sparser than the canonical MO coefficients; therefore, more efficient prescreening is possible. In this respect, the algorithm [128] is related to the local MP2 method. It appears, however, that due to the multiple transformations, the LT-MP2 method has a higher prefactor than the LMP2 method, which requires only a single transformation. On the other hand, the LT-MP2 method does not involve any truncation of the virtual space and therefore yields the exact canonical MP2 energy within a certain accuracy, which is primarily determined by the number of quadrature points and the prescreening thresholds used [122]. An LT linear-scaling coupled-cluster (LTCC) method was also developed and implemented for closed [134] and open [129] shells.

In Sects. 5.3 and 5.4, we consider Laplace-transform MP2 (LTMP2) and local MP2 (LMP2) methods extensions to periodic systems, implemented in computer

codes GAUSSIAN03 [102] and CRYSCOR (<http://www.theochem.unito.it/lcc2004/cryscor.pdf>), respectively. These two extensions are similar to their molecular counterparts in the preliminary calculation of delocalized canonical orbitals (Bloch functions for periodic systems) and further construction of localized crystalline orbitals (Wannier functions for periodic systems). However, the correlation effects for periodic systems may be taken into account in another way when the SCF calculations are made in Wannier-functions basis. Such an approach was named the incremental scheme [5, 47, 104] and is considered in the next section.

5.2 Incremental Scheme for Local Correlation in Periodic Systems

5.2.1 Weak and Strong Electron Correlation

In both molecules and solids, the electron correlation effects may be strong or weak. Let us consider an example of an H_2 molecule. For the two electrons involved, Heitler and London [141] suggested the following correlated ground-state wavefunction

$$\Psi_{HL}(\mathbf{r}_1\sigma, \mathbf{r}_2\sigma) = \frac{1}{N} [\chi_a(\mathbf{r}_1)\chi_b(\mathbf{r}_2) + \chi_b(\mathbf{r}_1)\chi_a(\mathbf{r}_2)] [\alpha_1\beta_2 - \alpha_2\beta_1] \quad (5.40)$$

where the AOs $\chi_a(\mathbf{r})$ and $\chi_b(\mathbf{r})$ are centered on atoms a and b of the molecule, and the spin functions α and β denote spin-up and spin-down states, respectively. One notes that this wavefunction does not contain ionic configurations in which two electrons are in the same atomic orbital $\chi_a(\mathbf{r})$ or $\chi_b(\mathbf{r})$. Therefore, their mutual Coulomb repulsion is minimal at the expense of the kinetic energy. The Heitler–London ansatz should work well when the Coulomb repulsion completely dominates the kinetic-energy gain caused by spreading an electron over both atoms. In this case, we speak of the strong correlation limit, and we expect it to be applicable, *for example*, when we stretch the H–H bond length to large values.

A very different ansatz applies when the opposite limit holds, *that is*, when the kinetic-energy gain due to spreading an electron over both atoms dominates the mutual electron repulsions. The molecular-orbital theory describes the two electrons within the independent electron approximation, and the bonding molecular orbital of an H_2 molecule is

$$\varphi(\mathbf{r}) = \frac{1}{N} [\chi_a(\mathbf{r}) + \chi_b(\mathbf{r})] \quad (5.41)$$

and it is occupied by the two electrons with opposite spins. Thus, the antisymmetric wavefunction is

$$\begin{aligned} \Psi_{MO}(\mathbf{r}_1, \sigma, \mathbf{r}_2, \sigma) = & \frac{1}{N} [\chi_a(\mathbf{r}_1)\chi_a(\mathbf{r}_2) + \chi_b(\mathbf{r}_1)\chi_b(\mathbf{r}_2) \\ & + \chi_a(\mathbf{r}_1)\chi_b(\mathbf{r}_2) + \chi_b(\mathbf{r}_1)\chi_a(\mathbf{r}_2)] [\alpha_1\beta_2 - \alpha_2\beta_1] \end{aligned} \quad (5.42)$$

Contrary to (5.40), the wavefunction (5.42) contains, with considerable weight, ionic configurations in which both electrons are at one H site. These configurations imply a large Coulomb repulsion between the two electrons. Therefore, the MO LCAO approximation will be a reasonable description of the true or exact wavefunction only when the energy gain due to hybridization of the atomic wavefunction is large as compared with the Coulomb repulsions. In reality, the ground-state wavefunction of H_2 has a form between (5.40) and (5.42). There are ionic configurations present, but their weight is partially suppressed as compared with (5.42). The partial suppression of charge fluctuations, *that is*, a reduction of the mean-square deviations of the electronic charges is a hallmark of electronic correlations. Charge fluctuations imply configurations in which the electronic charges deviate from the average charge distribution. When in a configuration of the H_2 molecule, both electrons are on one atomic site so that the other site is empty; the deviation from the average charge is as large as possible. In fact, we may use the degree of suppression of charge fluctuations as a measure of the strength of electron correlations. A complete suppression of charge fluctuations, as in the Heitler–London wavefunction, implies the strong correlation limit. From the above, it is obvious that we can learn much about electron correlations and their influence by studying the wavefunction of a system.

The solids with weak and with strong correlations require different methods of treatment. For example, when the correlations are weak, a wavefunction of independent electrons, *that is*, a self-consistent field (SCF) or Hartree–Fock (HF) wavefunction, seems a good starting point for the implementation of correlation corrections. In a solid, the molecular orbitals are replaced by crystalline (Bloch) orbitals. The latter are solutions of the SCF(HF) equations (4.57).

As we have pointed out above, a possible measure of the strength of electronic correlations is the degree of suppression of charge fluctuations in the true or correlated ground-state wavefunction as compared with those in a corresponding SCF or HF wavefunction. In order to obtain a feeling of how strong those suppressions are, we can calculate them for different chemical bonds [104]. Let Σ denote the ratio

$$\Sigma = \frac{\langle \Phi_{\text{SCF}} | \delta n^2 | \Phi_{\text{SCF}} \rangle - \langle \Psi_0 | \delta n^2 | \Psi_0 \rangle}{\langle \Phi_{\text{SCF}} | \delta n^2 | \Phi_{\text{SCF}} \rangle - \langle \Psi_{\text{PC}} | \delta n^2 | \Psi_{\text{PC}} \rangle} \quad (5.43)$$

where $\delta n^2 = n^2 - \bar{n}^2$ and $\bar{n}$ is the average electron number in an orbital being part of a bond, *for example*, $\bar{n} = 1$ in a carbon sp^3 orbital of a C–C σ -bond. The wavefunctions $|\Phi_{\text{SCF}}\rangle$, $|\Psi_0\rangle$ and $|\Psi_{\text{PC}}\rangle$ denote the HF ground state, the correlated or true ground state, and the ground state we would have if the energy gain due to delocalization, *that is*, moving an electron from atom to atom, were arbitrarily small. In $|\Psi_{\text{PC}}\rangle$, the charge fluctuations are reduced by the largest amount that is compatible with the charge distribution, *that is*, with the one-particle density matrix. A value of $\Sigma = 0$ implies no suppression of charge fluctuations and hence the limit of uncorrelated electrons, while $\Sigma = 1$ corresponds to the limit of strong electron correlations. For the H_2 molecule, $\Sigma = 0.15$, while for a C–C σ -bond $\Sigma \sim 0.2$,

indicating that electrons in diamond are weakly correlated. The same holds true for silicon. For a C–C π -bond, instead one finds $\Sigma \sim 0.5$, and correlations, *for example*, in polyacetylene, are fairly strong. When we consider the Cu–O planes of the perovskite-like La_2CuO_4 , we find that for a Cu site $\Sigma_{\text{Cu}} = 0.8$, while for an O site $\Sigma_{\text{O}} = 0.7$. Therefore, all Cu configurations different from $3d^{10}$ and $3d^9$ are essentially suppressed in $|\Psi_0\rangle$, while they still have an appreciable weight in $|\Psi_{\text{SCF}}\rangle$. More examples can be found in [5]. Reductions of electronic charge fluctuations as quantified by Σ can be described within a minimal basis set, *for example*, a set of s and p functions for the valence electrons of atoms of the second row. They are caused by interatomic correlations, and we refer to the latter when we speak of weakly or strongly correlated electrons. They should be distinguished from intra-atomic correlations that influence electrons on a given atomic site. They require a larger basis set for their description. At least one set of polarization functions must be included in this set, *for example*, a set of d functions in the case of atoms of the second row. For more details on these different types of correlations, we refer to reference [5]. In order to determine the correlated ground-state wavefunction $|\Psi_0\rangle$ for the solids with relatively weak correlations, one may start from the HF wavefunction $|\Phi_{\text{SCF}}\rangle$.

The wavefunction-based (post-Hartree–Fock) methods have received little attention in the electron correlation theory for crystals compared with those for molecular systems [104]. The progress in the electron correlation study in solids is connected mainly with density-functional theory (DFT), determining directly various physical properties of a system without a knowledge of the many-electron wavefunction. This feature makes DFT theory simpler and more attractive in the calculations of the electronic structure of crystals. Unfortunately, for the density-functional-based methods, there is no procedure for systematic improvement of the calculated results when a higher accuracy is desired. Although often ground-state properties of unexpected accuracy are obtained, this is not always the case, in particular when electron correlations in a crystal are strong. Various improvements that have been applied, like self-interaction corrections (SIC) or LDA + U [142–144], show that they remain essentially uncontrolled. On the other hand, today we can calculate electronic ground-state wavefunctions for small molecules with high precision, and there are controlled approximation schemes available for various degrees of accuracy. There is no reason why similar calculations cannot be done for solids; in fact, it has been demonstrated that they can [104]. It was already mentioned in Chap. 4 that accurate HF solutions for a variety of crystalline systems have been available for many years now [4, 145]. The clever exploitation of the full symmetry of the crystal and implementation of special algorithms for the exact or approximate estimate of infinite lattice sums permit the solution of big systems like faujasite (144 atoms, 1,728 AOs per unit cell) [146] to be obtained at quite low computational cost. However, the limitations of the HF approximation are well known, essentially due to its neglecting dynamical electron correlation.

The practical methods of post-HF calculations for solids were discussed during the workshop “Local correlation methods: from molecules to crystals” (<http://www.theochem.unito.it/lcc2004/>). Computational strategies were considered and new

developments suggested in this area of research (the texts of invited speaker talks are published on an Internet site <http://www.theochem.unito.it/lcc2004/>). In particular, it was stated that the development of post-HF methods for crystals is essentially connected with the progress in the localized Wannier-function (LWF) generation. In the last decade, LWF has been very intensively used in practical calculations of solids, see [147] and references therein. LWF for correlation calculations can be derived from Bloch states by a localization method as long as one does not have to deal with partially filled bands as in metals. There is also the possibility to generate LWFs directly from HF calculations, as is done in the computer code WANNIER [148].

In order to calculate the correlated ground state $|\Psi_0\rangle$ and its energy $\mathcal{E}_0$, we split the many-electron Hamiltonian H into

$$H = H_{\text{SCF}} + H_{\text{res}} \quad (5.44)$$

where H_{SCF} is the SCF part of the Hamiltonian and H_{res} is the residual interaction part. We may write

$$\mathcal{E}_0 = \frac{\langle \Phi_{\text{SCF}} | H | \Psi_0 \rangle}{\langle \Phi_{\text{SCF}} | \Psi_0 \rangle} \quad (5.45)$$

provided $\langle \Phi_{\text{SCF}} | \Psi_0 \rangle \neq 0$. This will be the case as long as we deal with finite systems.

It is worth mentioning that instead of dividing H as in (5.44), we could have split it also into a one-electron part H_{KS} corresponding to the Kohn–Sham equation in density-functional theory (see Chap. 7) and a remaining part. This has the advantage that the energy of the related ground state Ψ_{KS} , a Slater determinant constructed from solutions of the Kohn–Sham equation, is much closer to the true ground-state energy than is $\mathcal{E}_0$. Such a scheme may appear useful for the solids with the strong electron correlations and is used, for example, in the SIC and LDA+U approaches mentioned above. But, treating the remaining part H_{res} would not be interpretative as a correlation energy calculation in the sense that is traditional for molecular systems.

Treating a solid implies dealing with essentially infinitely many-electrons. However, in practice, we can correlate only a relatively small number of them. Therefore, we first have to reduce the calculations to a small number of electrons. This can be done by means of the method of increments considered in the next section.

5.2.2 Method of Increments: Ground State

A method of increments [105, 149, 150] is a wavefunction-based ab initio correlation method for solids. This method is closely related to the ideas of the local ansatz (LA), [5] where local operators acting on the SCF wavefunction are used to admix suitable one- and two-particle excitations to the mean-field HF ground state.

The many-electron Hamiltonian is split according to (5.44) and the ground-state Hamiltonian H_{SCF} , and the corresponding wavefunction $\Phi_{\text{SCF}} = \Phi_0$ is assumed to be known.

A product of two operators A and B in the Liouville space is defined as follows:

$$(A|B) = \langle \Phi_0 | A^\dagger B | \Phi_0 \rangle^c = (A^\dagger B)^c \quad (5.46)$$

The superscript c indicates that the cumulant of the expectation value is taken, which is given by

$$(A)^c = \langle A \rangle \quad (5.47)$$

$$\langle AB \rangle^c = \langle AB \rangle - \langle A \rangle \langle B \rangle \quad (5.48)$$

$$\vdots$$

By using (5.46), the exact ground-state energy E is written in the following way:

$$E = (H|\Omega) = E_{\text{HF}} + (H_I|\Omega) \quad (5.49)$$

where Ω plays the role of the wave operator that describes the transformation from the HF ground state to the exact ground state. For a solid with well-defined bonds, one can express the HF ground-state Φ_0 in terms of localized orbitals and label those orbitals by a bond index i . For ionic systems, this index numbers the ions whose states form the occupied bands (e.g., oxygen ions in MgO crystal).

The following operators are defined A_i , where i should be considered as a compact index that includes the bond i as well as the one- and two-particle excitations of bond i , and A_{ij} , which describes the two-particle excitations where one excitation is out of bond i while the other is out of bond j . Within the restricted operator subspace spanned by A_i and A_{ij} , the operator Ω can be written in the form

$$|\Omega) = \left| 1 + \sum_i n_i A_i + \sum_{\substack{ij \\ (i \neq j)}} n_{ij} A_{ij} \right) \quad (5.50)$$

The parameters n_i and n_{ij} in (5.50) are determined from the set of equations

$$\begin{aligned} 0 &= (A_k|H) + \sum_i n_i (A_k|HA_i) + \sum_{\substack{ij \\ (i \neq j)}} n_{ij} (A_k|HA_{ij}) \\ 0 &= (A_{kl}|H) + \sum_i n_i (A_{kl}|HA_i) + \sum_{\substack{ij \\ (i \neq j)}} n_{ij} (A_{kl}|HA_{ij}) \end{aligned} \quad (5.51)$$

where (5.50) was used.

The method of increments provides a scheme in which the set of equations (5.51) and hence the correlation energy are evaluated in a hierarchical order [149]:

- (a) First, all electrons are kept frozen except for those, *for example*, in bond i . The operators A_i describe the corresponding excitations of these two electrons and (5.51) reduces to

$$0 = (A_i|H) + n_i^{(1)}(A_i|HA_i) \quad (5.52)$$

Within this approximation, the $n_i^{(1)}$ are independent of each other and the correlation energy becomes

$$E_{\text{corr}}^{(1)} = \sum_i \epsilon_i \quad (5.53)$$

with

$$\epsilon_i = n_i^{(1)}(H_I|A_i) \quad (5.54)$$

- (b) In the next step the electrons in two bonds, *for example*, i and j , are correlated. The corresponding $n^{(2)}$ parameters are determined from the coupled equations

$$\begin{aligned} 0 &= (A_i|H) + n_i^{(2)}(A_i|HA_i) + n_j^{(2)}(A_i|HA_j) + n_{ij}^{(2)}(A_i|HA_{ij}) \\ 0 &= (A_j|H) + n_i^{(2)}(A_j|HA_i) + n_j^{(2)}(A_j|HA_j) + n_{ij}^{(2)}(A_j|HA_{ij}) \\ 0 &= (A_{ij}|H) + n_i^{(2)}(A_{ij}|HA_i) + n_j^{(2)}(A_{ij}|HA_j) + n_{ij}^{(2)}(A_{ij}|HA_{ij}) \end{aligned} \quad (5.55)$$

Again, the increments $\delta n_i = n_i^{(2)} - n_i^{(1)}$ and $\delta n_j = n_j^{(2)} - n_j^{(1)}$ are treated as independent of each other in this approximation, and we have

$$E_{\text{corr}}^{(2)} = \sum_i \epsilon_i + \frac{1}{2} \sum_{\substack{ij \\ (i \neq j)}} \Delta \epsilon_{ij} \quad (5.56)$$

where

$$\Delta \epsilon_{ij} = \epsilon_{ij} - (\epsilon_i + \epsilon_j) \quad (5.57)$$

and

$$\epsilon_{ij} = (H_I|n_i^{(2)}A_i + n_j^{(2)}A_j + n_{ij}^{(2)}A_{ij}) \quad (5.58)$$

- (c) Analogously, one calculates the three-bond energy increment, which is defined as

$$\Delta \epsilon_{ijk} = \epsilon_{ijk} - (\Delta \epsilon_i + \Delta \epsilon_j + \Delta \epsilon_k) + (\Delta \epsilon_{ij} + \Delta \epsilon_{jk} + \Delta \epsilon_{ik}) \quad (5.59)$$

The correlation energy ϵ_{ijk} is that obtained when all electrons are kept frozen except those in bonds i , j , and k . Again, the increments $\Delta \epsilon_{ijk}$ are treated as being independent of each other.

The total correlation energy within this approximation is the sum of all increments,

$$E_{\text{corr}}^{\text{solid}} = \sum_i \epsilon_i + \frac{1}{2} \sum_{\substack{ij \\ (i \neq j)}} \Delta\epsilon_{ij} + \frac{1}{6} \sum_{\substack{ijk \\ (i \neq j \neq k)}} \Delta\epsilon_{ijk} + \dots \quad (5.60)$$

It is obvious that by calculating higher and higher increments, the exact correlation energy within the coupled electron-pair approximation at level zero [151] is obtained.

The method of increments is useful only if the incremental expansion is well convergent, *that is*, if increments up to, say, triples are sufficient, and if increments become rapidly small with increasing distance between localized orbitals. These conditions were shown to be well met in the case of different solids [104, 152]. Ideally, the increments should be local entities not sensitive to the surroundings.

The theory described above has been applied to a great variety of materials, thus demonstrating the feasibility of calculations of that kind. These materials include the elemental semiconductors [149]; III–V [153] and II–VI compounds [154]; ionic crystals like MgO [155], CaO [156], and NiO [157]; alkali halides [158]; TiO₂ (with a sizeable amount of covalency) [159]; rare-gas crystals [160, 161]; solid mercury [162, 163], and the rare-earth compound GdN [164] with the 4*f* electrons kept within the core. The method of increments allows the CCSD local correlation scheme to be extended from molecules to solids. *In most cases*, the program package CRYSTAL [21] was used for the SCF part including a localization procedure for determining the Wannier functions. *An alternative approach* to CRYSTAL is an embedded-cluster approach called WANNIER, where the localization procedure is part of the SCF calculations. Thereby, the solid is modeled by a central cluster embedded in a field created by the remaining part of the infinite solid [148]. Test calculations at the SCF level for LiH agree very well with those obtained from CRYSTAL. For example, the difference in the SCF ground-state energy is only 0.05 eV per Li when a Li Wannier function extending over four and over three nearest-neighbors is used. Embedded-cluster calculations seem to be a very promising scheme for the future in order to perform high-quality electronic-structure calculations not only for solids but also for very large molecules. In the CeO₂ coupled-cluster calculations [165], several embeddings were tested: from purely point charges up to pseudopotential of surrounding oxygens to imitate the Ce ions. Embedded large nearly neutral clusters (Ce₄O₇) as well as several individual clusters, each of which consists of only correlated parts of the solid, were used in the calculations. Analysis of the obtained results allowed the conclusion that all tested embedding schemes should result in the same value of correlation energy. At the same time, a large neutral cluster seems to be the best choice for the embedding.

A *third way* of obtaining the SCF ground-state wavefunction is by means of an ordinary cluster calculation. In this case, a fragment of the crystal lattice is used. Its dangling bonds are saturated with hydrogen atoms when dealing with covalent solids, and it is surrounded by a large number of point charges when an ionic solid is treated. The wavefunction of the innermost bond or ion can be used to a good

approximation for every bond or ion of the solid. An example is $X_{35}H_{36}$ ($X = C, Si, Ge, Sn$), where the localized orbital for the central bond agrees with that obtained from CRYSTAL, after a localization procedure has been applied [104].

5.2.3 *Method of Increments: Valence-Band Structure and Bandgap*

The valence-band energies for solids can be regarded as energy differences between the N electron ground-state and a state with $(N - 1)$ electrons, where one delocalized Bloch electron has been removed. The bandgap can be regarded as the energy difference between the N -electron ground state and the state with $(N + 1)$ electrons, where one delocalized Bloch electron has been added. Fixing the number of electrons N in the ground state means that PBC are introduced for the main region of a crystal, *that is*, that the finite size system is considered.

At the SCF level, Koopmans' theorem holds, and the task of determining the band energies and energy gap can be reduced to finding the one-electron energies of the respective Bloch states. It is well known that SCF (HF) calculations tend to overestimate the energy gap, giving too low an energy for the top of the upper valence band and too high an energy of the conduction-band bottom. DFT, on the other hand, yields gaps that are far too small when using the common functionals such as LDA or GGA. To overcome this problem, several DFT-based or hybrid HF-DFT approaches were developed (see Chap. 7). As was already mentioned, DFT-based approaches do not provide clear concepts of systematically improving accuracy, and the numerical results essentially depend on the density-functional chosen.

The incremental scheme based on the wavefunction HF method was extended to the calculation of valence-band energies when the electron correlation is taken into account. In [166, 167], an effective Hamiltonian for the $(N - 1)$ -electron system was set up in terms of local matrix elements derived from multireference configuration-interaction (MRCI) calculations for finite clusters. This allowed correlation corrections to a HF band structure to be expressed and reliable results obtained for the valence-band structure of covalent semiconductors. A related method based on an effective Hamiltonian in localized Wannier-type orbitals has also been proposed and applied to polymers [168, 169]. Later, the incremental scheme was used to estimate the relative energies of valence-band states and also yield absolute positions of such states [170]. This is important as a prerequisite for the determination of bandgaps. Unfortunately, a further extension of the formalism to also cover conduction-band states (which would complete the information on bandgaps) is not possible along the same lines.

This is because an effective Hamiltonian for $(N + 1)$ -particle states cannot be extracted from finite-cluster calculations (which do not lead to stable states for the extra electron). Instead, a scheme for the calculation of localized states in infinite periodic surroundings is necessary [106, 171]. However, the information

on the correlation-induced shift of the absolute position of the upper valence-band edge already allows for an estimate of correlation effects on bandgaps. In a reasonable approximation, one can assume that correlation effects for the process of removing one electron, and the inverse process of adding an extra electron, are almost symmetric. This approximation seems plausible in view of the fact that the dominant effect of correlations caused by an added electron (hole) is the generation of a long-ranged polarization cloud. The latter moves with the added particle and together with it forms a quasiparticle. A simple estimate of the corresponding gap correction is obtained by calculating the classical polarization-energy gain in a continuum approximation. This is given in [5]

$$\delta E = \frac{1}{2} \int d^3r \mathbf{P} \cdot \mathbf{E} = -\frac{\epsilon_0 - 1}{2\epsilon_0} \frac{e^2}{l_c} \quad (5.61)$$

where $\mathbf{P}$ is the macroscopic polarization, $\mathbf{E}$ is the electric field generated by the extra particle and ϵ_0 is the dielectric constant of the medium. The cutoff l_c is approximately equal to the length at which the dielectric function, $\epsilon(r)$, reaches its asymptotic value, ϵ_0 , as a function of the distance, r , from the extra particle. The contribution, δE is approximately the same for an added electron and an added hole because l_c should be nearly equal in both cases. Therefore, this assumption can be considered as physically justified, and indeed, final estimates for the correlation-induced reduction of bandgaps compare reasonably well with experiment [170].

The incremental scheme for the valence band rests on the observation that an HF-hole can be either described in reciprocal or in direct space. In reciprocal space, the $(N - 1)$ -electron states are introduced

$$|k\nu\sigma\rangle = a_{k\nu\sigma}|\Phi_{scf}\rangle \quad (5.62)$$

where $a_{k\nu\sigma}$ annihilates an electron with wave vector $\mathbf{k}$ and spin σ in band ν of the HF-determinant $|\Phi_{scf}\rangle$ of the neutral system in the ground state (the spin index will be suppressed as the spinless HF Hamiltonian is supposed to be considered). According to Koopmans' Theorem, its HF one-electron energies can be written in the form

$$\varepsilon_{k\nu}^{scf} = E_0^{scf} - \langle k\nu | H | k\nu \rangle \quad (5.63)$$

where E_0^{scf} is the HF ground-state energy.

The states $|k\nu\rangle$ can be approximated in terms of basis functions adapted to translational symmetry, with creation—annihilation operators $b_{kn}^\dagger, b_{kn}$:

$$a_{k\nu} = \sum_n d_{\nu n} b_{kn} \quad (5.64)$$

The coefficients $d_{\nu n}$ are found by diagonalizing the matrix

$$H_{nn'}^{scf}(\mathbf{k}) = \langle \mathbf{k}n | E_0^{scf} - H | \mathbf{k}n' \rangle \quad (5.65)$$

where $|\mathbf{k}n\rangle = b_{kn}|\Phi_{scf}\rangle$ are assumed to be orthogonal, for simplicity.

To base considerations on states with localized extra electrons or holes, the Wannier-type transformation is introduced, yielding localized states within each unit cell. The number of these states equals the number of bands included in the Wannier transformation. In the case of elemental semiconductors such as diamond or silicon, these are one-electron states localized at the middle of the nearest atom bonds so that $n = 1, 2, 3, 4$ (see Chap. 3 for the discussion of the connection between Bloch and Wannier states). A local description arises through the decomposition of the b_{kn} into a sum of local operators marked with a cell index $\mathbf{R}$ (translation vector of the direct lattice):

$$b_{kn} = \frac{1}{\sqrt{N}} \sum_{\mathbf{R}} \exp(-i\mathbf{k} \cdot \mathbf{R}) c_{\mathbf{R}n} \quad (5.66)$$

The operator $c_{\mathbf{R}n}$ annihilates an electron in a local basis function centered in cell $\mathbf{R}$. The sum in (5.66) is precisely the projector onto the irreducible representation $\mathbf{k}$ of the translation group. In this basis, the matrix (5.65) becomes

$$H_{nn'}^{\text{scf}}(\mathbf{k}) = \sum_{\mathbf{R}} \exp(-i\mathbf{k} \cdot \mathbf{R}) \langle 0n | E_0^{\text{scf}} - H | \mathbf{R}n' \rangle \quad (5.67)$$

which can be obtained by the direct-space quantities $\langle 0n | H | \mathbf{R}n' \rangle$. Without loss of generality, the functions annihilated by the $c_{\mathbf{R}n}$ can be chosen as localized orbitals spanning the occupied HF space of the neutral system, *that is*, as localized two-center bond orbitals for covalent semiconductors. In this case, $\langle 0n | H | \mathbf{R}n' \rangle$ represents the hopping matrix element between an HF-hole located in the central cell in bond n to a bond n' in cell $\mathbf{R}$. The direct lattice formalism allows for inclusion of local correlation effects. Such effects are obtained when the HF states $|\mathbf{R}n'\rangle$ are replaced by their correlated counterparts $|\mathbf{R}n'\rangle$, and E_0^{scf} is replaced by the true ground-state energy, E_0 .

An incremental scheme application to valence bands requires computing the correlated nondiagonal matrix elements $\langle 0n | H | \mathbf{R}n' \rangle$ in terms of a rapidly converging series of approximations. Figure 5.1 shows the correlated valence-band structure for Si with and without correlation, taken from [167]. The energy at the top of the valence band in both cases has been set to zero. The local matrix elements were extracted from calculations of a set of small molecules $X_n H_m$ and used to set up an incremental expansion of the bulk band structure.

For computing the absolute shift of the valence bands, one needs to consider also the diagonal matrix element

$$\{0n | H | 0n'\} \quad (5.68)$$

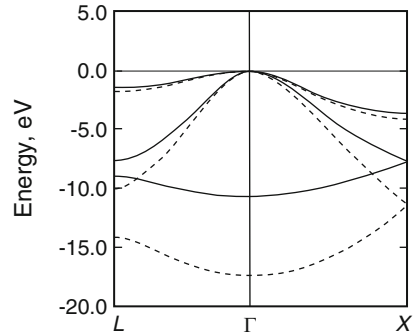
Such a calculation is discussed in detail in [170]. First, an HF-hole is considered in a specific localized bond orbital B_i of a finite cluster simulating the crystalline semiconductor, with B_i representing $|0i\rangle$.

Let ϵ_i^{scf} denote the HF value of a hole in this particular bond B_i :

$$\epsilon_i^{\text{scf}} = \langle B_i | E_0^{\text{scf}} - H | B_i \rangle \quad (5.69)$$

As a first step, correlation calculations are performed both for the neutral cluster and for the cluster with a hole in bond B_i by restricting electron excitations to excitations

Fig. 5.1 The SCF (*dashed lines*) and correlated (*solid lines*) band structure for silicon, [167]



out of this bond only. The energy difference, $\epsilon_i^{\text{intra}}$, between the correlated energies of the neutral and the charged cluster is then an excitation energy improved with respect to the HF value (5.69) by the inclusion of correlation effects. The difference

$$\Delta_i^{\text{in}} = \epsilon_i^{\text{intra}} - \epsilon_i^{\text{scf}} \quad (5.70)$$

constitutes the “intrabond” increment of the correlation corrections to the diagonal element. In the next step, correlations are taken into account by releasing electrons out of two bonds, namely, the one that contains the hole, B_i and one additional bond B_j . Again, a reference calculation is needed for the neutral cluster, where electrons are excited out of these two bonds. Let us denote the corresponding energy with $E_{i;j}^0$. For the case with a hole, a multireference configuration-interaction (MRCI) calculation is performed where the two HF determinants that contain the HF-hole in bond B_i and bond B_j , respectively, are the reference functions forming the model space. The calculation results in a diagonal (2×2) -eigenenergy matrix with eigenvalues λ_1 and λ_2 and corresponding eigenvectors $|\Psi_1\rangle$ and $|\Psi_2\rangle$. Due to the diagonalization in the course of the correlation treatment, the two eigenvectors are delocalized over the region spanned by the two bonds considered. To get the matrix element of the Hamiltonian between the local states, as in (5.69), the diagonal representation of H given by the eigenenergies is rotated back into a local matrix representation. To do so, the eigenvectors are projected onto the model space to give the reduced eigenvector matrix, $\underline{\mathbf{D}}$:

$$\underline{\mathbf{D}} = \begin{pmatrix} \langle B_i | \Psi_1 \rangle & \langle B_i | \Psi_2 \rangle \\ \langle B_j | \Psi_1 \rangle & \langle B_j | \Psi_2 \rangle \end{pmatrix} \quad (5.71)$$

Due to this projection, the two eigenvectors contained in (5.71) are not strictly orthonormal but can be made so by means of Löwdin symmetric orthonormalization ($\underline{\mathbf{D}} \rightarrow \widetilde{\underline{\mathbf{D}}}$). The matrix

$$\underline{\mathbf{M}} = \widetilde{\underline{\mathbf{D}}} \begin{pmatrix} E_{i;j}^0 - \lambda_1 & 0 \\ 0 & E_{i;j}^0 - \lambda_2 \end{pmatrix} \widetilde{\underline{\mathbf{D}}}^\dagger \quad (5.72)$$

gives the matrix representation of H in local states. The diagonal element of this matrix corresponding to the bond B_i is the correlated value of one-electron energy (5.69) taking into account the effect of correlation of one additional bond B_j . The procedure can be extended to include further increments. Double-bond increments contain the effect of considering two additional bonds B_j and B_k , while the triple-bond increments include three further bonds B_j , B_k , and B_l .

The mainly local character of the correlation effects manifests itself in a rapid decrease of the magnitude of the increments, both with regard to the number of bonds and distances between them. This allows the numerical effort for the calculation to be reduced to just a few increments, which can be evaluated for a finite (embedded) cluster. In [170], it is demonstrated that for diamond and silicon crystals, the largest correlation correction comes from the single excitations of the increment called SB1 that takes into account 66% and 64% of the overall correlation effect, respectively. Thus, the polarization of the first coordination sphere, stabilizing the ionized system, gives by far the most important separate correlation effect.

The bonds B_i used in the formulation of the incremental scheme above can be obtained by an HF calculation for such a finite cluster with an a posteriori Boys localization [36], which directly yields the bonds as localized HF orbitals. All increments were derived in [170] from the cluster calculations. C and Si clusters dangling bonds were suppressed by the introduction of hydrogen atoms. The electron correlations dramatically reduce the diagonal elements from their HF eigenvalues -0.68 , -0.51 Hartree to -0.45 , -0.34 Hartree, for C and Si, respectively. When these values of the diagonal matrix element are fed into a band-structure calculation, the absolute shift of the valence bands due to electronic correlations is obtained. The above results lead to a shift of the upper valence band at the Γ -point of 3.90 eV for C and 2.63 eV for Si. To compare these results with experiment, we note that in diamond, the HF-gap at the Γ -point has been calculated as 13.8 eV [172], while the experimental one is 7.3 eV. If one attributes the reduction of 6.5 eV in equal parts to the shift of the conduction and the valence band, each shift should amount to 3.3 eV, so we overestimate the shift by 0.6 eV. In the case of Si, the (direct) HF-gap at the Γ -point of 8.4 eV [172] is too large by 5.0 eV, as compared to the corresponding experimental value of 3.4 eV, which would attribute a share of 2.5 eV to the valence-band shift. The result obtained in [170] of 2.6 eV nearly coincides with this shift. The deviation of these estimates for diamond from the experimental value can be explained by the crude assumption of a symmetric contribution, both for the valence and for the conduction band, to the closing of the direct HF-gap.

Different approaches to the problem of excitations in correlated electron systems are considered in [173]. They are based on a quasiparticle description when electron correlations are weak and on a Green's function or projection operator approach when they are strong. In both cases, intersite correlation contributions to the energy bands require special attention.

It is shown that for both small and large correlation energy contributions, the method of increments reduces the amount of computations decisively.

In [152], a critical review of the incremental scheme of obtaining the energetic properties of extended systems from wavefunction-based *ab initio* calculations of small (embedded) building blocks is given, which has been applied to a variety of van der Waals-bound (solid Xe), ionic (MgO), and covalent (C and Si) solids in the past few years. Its accuracy is assessed by means of model calculations for finite systems, and the prospects for applying it to delocalized systems are given. The individual determination of the increments of the many-body expansion leads, on the other hand, to the possibility of determining these increments in small finite model systems where a suitable embedding makes the orbitals of a given building block (or pairs, triples, *etc.*, of building blocks) similar to those of the extended one. This efficiently reduces the computational effort and obviates the necessity of restricting excitations to the virtual space (by introducing a domain structure) as in the local-correlation methods. This also means that the many-body expansion approach can be used with every quantum-chemical program package.

The correlated band structure of the one-periodic systems (polymers) was efficiently studied using the AO Laplace-transformed MP2 theory discussed in the next section.

5.3 Atomic Orbital Laplace-Transformed MP2 Theory for Periodic Systems

5.3.1 Laplace MP2 for Periodic Systems: Unit-Cell Correlation Energy

In [174], explicit expressions were presented for electron correlation at the MP2 level and implemented for the total energy per unit cell and for the band structure of extended systems. Using MP2 for E^N , E^{N-1} , E^{N+1} (the total energies of one-determinant states for N , $(N - 1)$ - and $(N + 1)$ -electron systems), a formula was presented for a direct evaluation of the bandgap rather than obtaining it as a difference of two large numbers. The formulation was given in the conventional crystalline orbitals delocalized over the whole extended system. Later [175] this theory for periodic systems was reformulated. The unit-cell MP2 energy was evaluated by Laplace transforming the energy denominator and heavily screening negligible contributions in the AO formulation. This is the extension to periodic systems of the AO Laplace-transformed formulation applied earlier for molecules in [176, 177]. This Laplace MP2 real-space approach avoids the high computational cost of multidimensional wavevector $\mathbf{k}$ integrations that is critical in order to obtain accurate estimates. It is efficient to treat one-, two- and three-periodic crystals (1D, 2D, and 3D systems, respectively). The benchmark calculations [175, 178] were carried out for polymers (1D) and hexagonal BN plane (2D) as well as stacked 1D polymers. The HF portion of calculations was carried out using a PBC option of the molecular computer code Gaussian03 [102].

Here, we briefly present the main points of Laplace MP2 theory for periodic systems.

Equation (5.30) for the correlation energy in the MP2 approximation for molecules can be written in the form

$$E_2 = - \sum_{ij,ab}^{\text{Occ, Vir}} \frac{(ia|jb)[2(ia|jb) - (ib|ja)]^*}{\epsilon_a + \epsilon_b - \epsilon_i - \epsilon_j} \quad (5.73)$$

where ϵ_i and ϵ_a are HF energies of the canonical occupied and virtual MOs, respectively. The two-electron integrals in the canonical MO basis, $(ia|jb)$, are obtained by transformation of the Coulomb two-electron integrals in the atom-centered Gaussian-type orbital basis,

$$\begin{aligned} (ia|jb) &= \int i(1)j(2) \frac{1}{r_{12}} a(1)b(2) d\mathbf{r}_1 d\mathbf{r}_2 \\ &= \sum_{\mu\nu\lambda\sigma} (\mu\nu|\lambda\sigma) C_{\mu i}^* C_{\nu a} C_{\lambda j}^* C_{\sigma b} \end{aligned} \quad (5.74)$$

For periodic systems, the MP2 correlation energy correction is given by an expression very similar to the molecular case [174]; the only difference is the use of the crystalline Bloch (canonical) orbitals instead of MOs:

$$\begin{aligned} E_2 &= -Re \left[\frac{1}{V_k^4} \int d\mathbf{k}_1 d\mathbf{k}_2 d\mathbf{k}_3 d\mathbf{k}_4 \sum (i(\mathbf{k}_1)a(\mathbf{k}_3)|j(\mathbf{k}_2)b(\mathbf{k}_4)) \right. \\ &\quad \times \left. \frac{2(i(\mathbf{k}_1)a(\mathbf{k}_3)|j(\mathbf{k}_2)b(\mathbf{k}_4)) - (i(\mathbf{k}_1)b(\mathbf{k}_4)|j(\mathbf{k}_2)b(\mathbf{k}_3))^*}{\epsilon_a(\mathbf{k}_3) + \epsilon_b(\mathbf{k}_4) - \epsilon_i(\mathbf{k}_1) - \epsilon_j(\mathbf{k}_2)} \right] \end{aligned} \quad (5.75)$$

The generalization to a spin unrestricted formalism is done in a similar fashion as in the molecular case.

The two-electron integrals in the energy formula are now complex and given by

$$\begin{aligned} (i(\mathbf{k}_1)a(\mathbf{k}_3)|j(\mathbf{k}_2)b(\mathbf{k}_4)) &= \sum_{pqrs} \sum_{\mu\nu\lambda\sigma} (\mu_p \nu_q | \lambda_r \sigma_s) C_{\mu i}^* C_{\nu a} C_{\lambda j}^* C_{\sigma b} \\ &\quad \times \exp [i(-\mathbf{k}_1 p + \mathbf{k}_3 q - \mathbf{k}_2 r + \mathbf{k}_4 s) \cdot \mathbf{g}] \end{aligned} \quad (5.76)$$

Here, the subscripts p, q, r, s indicate which cell the particular AO belongs to.

Provided that the energy denominator is a strictly positive quantity, the Laplace-transform can be used to write

$$\begin{aligned} &\frac{1}{\epsilon_a(\mathbf{k}_3) + \epsilon_b(\mathbf{k}_4) - \epsilon_i(\mathbf{k}_1) - \epsilon_j(\mathbf{k}_2)} \\ &= \int \exp [(-\epsilon_a(\mathbf{k}_3) - \epsilon_b(\mathbf{k}_4))t] \exp [(\epsilon_i(\mathbf{k}_1) + \epsilon_j(\mathbf{k}_2))t] dt \end{aligned} \quad (5.77)$$

The central feature of the transformed energy denominator is that the indices and attached quantities that were coupled by the denominator are now decoupled, allowing a reordering of the summations. In particular, the four different $\mathbf{k}$ -integrations can be carried out independently of each other, yielding the following unit-cell MP2 correlation energy formula (where repeated Greek indices are contracted):

$$\begin{aligned} E_2 &= \int \sum_{prs} T_{\mu_0 \lambda_r}^{v_p \sigma_s}(t) [2(\mu_0 v_p | \lambda_r \sigma_s) - (\mu_0 \sigma_s | \lambda_r v_p)] dt \\ &= \int \sum_{prs} T_{\mu_0 \lambda_r}^{v_p \sigma_s}(t) v_{v_p \sigma_s}^{\mu_0 \lambda_r} dt \end{aligned} \quad (5.78)$$

where the amplitudes T of the Coulomb integrals are transformed by the Fourier-transformed weighted density and complimentary matrices X and Y , respectively.

$$\begin{aligned} T_{\mu_0 \lambda_r}^{v_p \sigma_s}(t) &= X_{\mu_0 \gamma_t} Y_{v_p \delta_u} (\gamma_t \delta_u | \kappa_v \epsilon_w) X_{\lambda_r \kappa_v} Y_{\sigma_s \epsilon_w} \\ &= (\underline{\mu}_0 \bar{v}_p | \underline{\lambda}_r \bar{\sigma}_s) \end{aligned} \quad (5.79)$$

where

$$\begin{aligned} X_{\mu_p \gamma_s} &= \frac{1}{V_k} \int \sum_j C(\mathbf{k})_{\mu j} \exp(-\epsilon_j(\mathbf{k})t) C(\mathbf{k})_{\gamma j} \\ &\quad \times \exp[i\mathbf{k} \cdot (\mathbf{p} - \mathbf{s})] d\mathbf{k}, \\ Y_{\mu_p \gamma_s} &= \frac{1}{V_k} \int \sum_a C(\mathbf{k})_{\mu a} \exp(\epsilon_a(\mathbf{k})t) C(\mathbf{k})_{\gamma a} \\ &\quad \times \exp[i\mathbf{k} \cdot (\mathbf{p} - \mathbf{s})] d\mathbf{k} \end{aligned} \quad (5.80)$$

In matrix elements (5.80), the summation runs over the occupied states (j) and virtual states (a), respectively. $C(\mathbf{k})_{\mu j}$ and $C(\mathbf{k})_{\mu a}$ are the expansion coefficients on the atomic basis for states j and a at point $\mathbf{k}$. V_k is the volume of the first Brillouin zone, where integration over $\mathbf{k}$ is performed.

By comparing the expression (5.78) for the MP2 correlation energy to the canonical reciprocal-space expression (5.75), it becomes clear that the multidimensional quasimomentum integration has been reduced to a series of independent Fourier transforms (5.80). For all practical purposes, the computational cost of calculating the MP2 correlation energy in the AO basis is independent of the number of $\mathbf{k}$ -points used in the Brillouin-zone integration. Very dense $\mathbf{k}$ -point meshes can be used at little extra cost, and thus convergence issues found in earlier [174] reciprocal-space MP2 implementations are avoided. As was shown in [179], the interactions between atoms in the central cell (cell 0) and atoms in the neighboring cells can be quantified by considering the atoms the basis functions in (5.78) are centered on. In the case of periodic MP2 theory, it is particularly interesting to consider a cell-pair partitioning,

$$E_2 = \sum_{\mathbf{r}} e_2^{0\mathbf{r}} \quad (5.81)$$

$$e_2^{0\mathbf{r}} = \int \sum_{\mathbf{p}\mathbf{s}} T_{\mu_0\lambda_r}^{\nu_p\sigma_s}(t) [2(\mu_0\nu_p|\lambda_r\sigma_s) - (\mu_0\sigma_s|\lambda_r\nu_p)] dt \quad (5.82)$$

Whereas for $e_2^{0\mathbf{r}}$ the contributions from cells $\mathbf{p}$ and $\mathbf{s}$ decay exponentially with intercell distance between $\mathbf{0}$ and $\mathbf{r}$, the correlation contribution from $e_2^{0\mathbf{r}}$ itself decays quickly, with respect to $|\mathbf{o} - \mathbf{r}|$ distance.

It has been shown for molecules [179] that the expected $1/R^6$ decay of distant correlation contributions is closely modeled by the atom-pair partitioning. The same type of decay is also observed in the periodic case, and $e_2^{0\mathbf{r}}$ decays as $1/|\mathbf{o} - \mathbf{r}|^6$. Of course, the extent of the lattice summations over $\mathbf{p}\mathbf{r}\mathbf{s}$ in (5.78) greatly affects both the computational cost and the accuracy of the calculation. By taking advantage of the spatial decay properties mentioned above, the energy contraction can be carried out only for cells such that $|\mathbf{o} - \mathbf{r}| \leq r_{\max}$, while the $\mathbf{p}$ and $\mathbf{s}$ lattice summation truncations must be controlled [175].

The smooth decay of the energy contributions in the contraction can, of course, be used to safely truncate the lattice summation. For example, the central cell energy contribution $e_2^{0\mathbf{r}}$ provides a good estimate for the contribution from distant cells. In most cases, the magnitude $e_2^{0\mathbf{r}}$ is reasonably well approximated by $e_2^{00}/|\mathbf{o} - \mathbf{r}|^6$. A system with a unit-cell translation length of 2.5 Å can, thus, be expected to have no significant contribution to the correlation energy contraction beyond approximately the fifth or sixth neighboring cell. However, although relatively few cells need to be considered in the energy contraction ($r_{\max} = 4$ –6 cells for 1D systems such as polyacetylene, typically), the spatial framework of duplicated cells needs to be large enough so that all significant charge distributions, including the ones centered near the edge, are properly expanded.

5.3.2 Laplace MP2 for Periodic Systems: Bandgap

To correct the HF bandgap at the MP2 level, the quasiparticle energy formalism was applied [175, 178]. The quasiparticle (MP2) energies for a given state g are given by (closed-shell case)

$$\epsilon_g^{\text{MP2}} = \epsilon_g + U(g) + V(g) = \epsilon_g + \Delta\epsilon_g^{\text{MP2}} \quad (5.83)$$

$$U(g) = - \sum_{i,a,b} \frac{(ia|gb) [2(ia|gb) - (ib|ga)]}{\epsilon_a + \epsilon_b - \epsilon_i - \epsilon_g} \quad (5.84)$$

$$V(g) = \sum_{i,j,a} \frac{(ia|jb) [2(ia|jb) - (ig|ja)]}{\epsilon_a + \epsilon_g - \epsilon_i - \epsilon_j} \quad (5.85)$$

where i and j are occupied, and a and b are unoccupied HF orbitals of the system. Consequently, ϵ_i, ϵ_j , and ϵ_a, ϵ_b are occupied and unoccupied HF-orbital energies, respectively. In a finite-basis calculation, the number of virtual orbitals is finite and determined by the basis set. The Laplace-transform of the energy denominators is applied to Eqs. (5.84) and (5.85), and using an AO basis formulation, one obtains

$$\Delta\epsilon_g^{\text{MP2}} = \int_0^\infty dt \sum_{\mu_0\lambda_r\nu_p\sigma_s} G_{\mu_0\lambda_r}^{\nu_p\sigma_s}(t) v_{\mu_0\lambda_r}^{\nu_p\sigma_s} \quad (5.86)$$

where

$$v_{\mu_0\lambda_r}^{\nu_p\sigma_s} = 2(\mu_0\lambda_r|\nu_p\sigma_s) - (\mu_0\sigma_s|\nu_p\lambda_r)$$

$$(\mu_0\lambda_r|\nu_p\sigma_s) = \int d\mathbf{r}_1 d\mathbf{r}_2 |\mathbf{r}_1 - \mathbf{r}_2|^{-1} \mu_0(\mathbf{r}_1) \lambda_r(\mathbf{r}_1) |\nu_p(\mathbf{r}_2) \sigma_s(\mathbf{r}_2) \quad (5.87)$$

are two-electron integrals of AOs, for orbitals centered on cells with real-space coordinates $\mathbf{0}, \mathbf{r}, \mathbf{p}$, and $\mathbf{s}$, respectively. All real-space integrations are performed over all space. $\Delta\epsilon_g^{\text{MP2}}$ is the MP2 correction to the HF eigenvalue as defined in (5.83). The other required quantity in (5.86) is

$$G_{\mu_0\lambda_r}^{\nu_p\sigma_s}(t) = \sum_{\gamma_t \delta_u \kappa_v \varepsilon_w} X_{\mu_0\gamma_t}^t Y_{\nu_p\delta_u}^t (\gamma_t \delta_u | \kappa_v \varepsilon_w) \\ \times [W_{\lambda_r\kappa_v}^t Y_{\sigma_s\varepsilon_w}^t + X_{\lambda_r\kappa_v}^t Z_{\sigma_s\varepsilon_w}^t] \quad (5.88)$$

The elements of the X and Y matrices are given in (5.80). The elements of the W and Z matrices are defined by

$$W_{\mu_p\gamma_s}^t = C(\mathbf{k}^\dagger)_{\mu_g} \exp[-\epsilon_g(\mathbf{k}^\dagger)t] C(\mathbf{k}^\dagger)_{\gamma_g} \exp[\mathbf{k}^\dagger(\mathbf{p} - \mathbf{s})] \quad (5.89)$$

$$Z_{\mu_p\gamma_s}^t = -C(\mathbf{k}^\dagger)_{\mu_g} \exp[\epsilon_g(\mathbf{k}^\dagger)t] C(\mathbf{k}^\dagger)_{\gamma_g} \exp[\mathbf{k}^\dagger(\mathbf{p} - \mathbf{s})] \quad (5.90)$$

where for evaluating the correction to the bandgap, W and Z are constructed from the highest-occupied crystal orbitals (HOCO) and lowest-unoccupied crystal orbitals (LUCO) at point $\mathbf{k}$ at which the bandgap is minimum. Note that adding a constant value (*e.g.*, the Fermi energy) to all occupied orbital energies and subtracting the same value from all virtual orbital energies does not affect the denominators of (5.84) and (5.85) nor the MP2 corrections, but they guarantee that all the integrals containing terms such as $\exp[-\epsilon_i(\mathbf{k})t]$ and $\exp[-\epsilon_a(\mathbf{k})t]$ are finite. Depending on whether g is the HOCO or the LUCO, $U(g(\mathbf{k})) + V(g(\mathbf{k}))(g(\mathbf{k}))$ corresponds to the MP2 correction to the ionization potential or the electron affinity. The subtraction of these two corrections, in the spirit of Koopman's theorem, yields the correction to the bandgap. Indirect bandgaps are obtained in a similar fashion by considering two different $\mathbf{k}$ -points.

Finally, (5.86) is approximated by numerical Gauss–Legendre quadrature after a logarithmic transform of the t variable

$$\Delta\epsilon_g^{\text{MP2}} \approx \sum_n \omega_n \sum_{\mu_0\lambda_r\nu_p\sigma_s} G_{\mu_0\lambda_r}^{\nu_p\sigma_s}(t_n) v_{\mu_0\lambda_r}^{\nu_p\sigma_s} \quad (5.91)$$

where t_n and ω_n are the quadrature points and weights, respectively. Usually 3–5 points are enough to evaluate the gap corrections, although more are necessary for the energy [178].

The Laplace MP2 method is applied in [175] for the calculation of the correlation corrections to the bandgap in 1D and 2D systems. Let us consider the results for a 2D system—hexagonal boron nitride in a one-layer model. Like graphite, BN can exist in the form of nanotubes. Because these nanotubes can be viewed as hexagonal BN sheets rolled onto themselves, hexagonal boron nitride has been the object of renewed interest. The main absorption of a thin film of hexagonal BN is found at 6.2 eV, and a sharp fall at about 5.8 eV was attributed to the direct bandgap on the basis of semiempirical calculations [180]. The quasiparticle band energy structure at both the Hartree–Fock and the correlated level was calculated in [181] using a method very similar to MP2, the second-order many-body Green-function approach. Hexagonal BN was shown to have a rather complex band structure. Points P and Q are two high-symmetry points within a Brillouin zone with hexagonal symmetry—the hexagon corner and center of edge, respectively. The HF bandgap is minimum at $\mathbf{k}$ -point P and was evaluated to be 12.46 eV and the quasiparticle gap to be 2.88 eV. At point Q, the HF-gap is 16.45 eV, and correlation was said to decrease it to 6.48 eV.

PBC MP2 calculations [175] have been unable to corroborate these results. In these calculations, the HF band structure was shown to have a minimum bandgap of 13.73 eV at a point that is neither P nor Q, but rather in between, at a point of higher symmetry still. After examination of the phases of the Bloch orbitals at these points, one can say that point P is best characterized as corresponding to a trans alternation, whereas Q corresponds to a cis alternation. Laplace MP2 calculation, thus, seems to indicate first, that the Hartree–Fock method favors a form that is a mixture of these two distinct alternations and second, that for a meaningful calculation, great care should be taken in the convergence of the HF density by using an appropriate $\mathbf{k}$ -mesh and spatial framework. The correlation correction to the bandgap is very important, as suggested by the MP2 studies. Using 5 Laplace quadrature points and 49 cells to carry out the final contraction, the MP2 gap correction is –6.25 eV. The direct MP2 bandgap can be thus estimated to be at most 7.5 eV, approximately 1.5 eV above the experimental absorption peak. This constitutes a rather good agreement given that much larger basis sets would be needed to properly describe the conduction band that is thought to have a very large extent into the vacuum region.

The Laplace MP2 algorithm of a correlated band-structure calculation is discussed in [178] and applied to trans-polyacetylene.

The post-HF methods for periodic systems were discussed in Sects. 5.2 and 5.3. The incremental technique and the Laplace MP2 approach can be mentioned as the most successful approaches to the correlation in solids [5, 182]. The former uses standard molecular codes with clusters of various shapes and sizes to calculate the correlation energy, the latter adopts a formulation of correlation directly in AO basis.

The incremental scheme can be realized using the different post-Hartree–Fock methods (MP2, coupled-cluster CCSD(T)). This scheme is applicable both for nonconducting crystals and metals. The use of finite clusters allows modern sophisticated molecular codes to be applied (like MOLPRO code <http://www.molpro.net>). The incremental scheme can be used not only for calculation of the energy but also for the energy gradients necessary in the atomic-structure optimization. Unfortunately, the application of the incremental scheme requires some “hand” work when choosing the cluster size and shape for any new system. To the best of our knowledge the code WANNIER (for crystals) [148] allows consideration only of the crystals with a small number of atoms in the unit cell. If clusters are used instead of crystals, the finite nature of the system under consideration affects the results. It is not so easy to set a reasonable cluster to approximate a crystal, especially when there are many atoms in the unit cell. We do not think that these disadvantages are intrinsic features of the incremental scheme but are mainly connected with the necessity of some standard code generation.

The essential advantage of the Laplace MP2 method is its incorporation in publicly available Gaussian03 [102] computer code with PBC introduction for HF calculations. Due to the Laplace-transform, the dense grids of $\mathbf{k}$ -points can be afforded; the virtual space is not truncated so the method gives the true MP2 energy. The Laplace MP2 band structure can be calculated, including the correlation correction to the bandgap. As no results of its application to 3D systems were published, it is difficult to judge how reliable this method is for three-dimensional crystals.

In the next section, we consider a local MP2 scheme for periodic systems that is now incorporated in more or less “standard” CRYSCOR correlation computer code for nonconducting crystals [103].

5.4 Local MP2 Electron Correlation Method for Nonconducting Crystals

5.4.1 Local MP2 Equations for Periodic Systems

The local MP2 electron correlation method for nonconducting crystals [103] is an extension to crystalline solids of the local correlation MP2 method for molecules (see Sect. 5.1.5), starting from a local representation of the occupied and virtual HF subspaces. The localized HF crystalline orbitals of the occupied states are provided in the LCAO approximation by the CRYSTAL program [21] and based on a Boys

localization criterion. The localization technique was considered in Sect. 3.3.3. The label im of the occupied localized Wannier functions (LWF) $W_{im} = W_i(\mathbf{r} - \mathbf{R}_m)$ includes the type of LWF and translation vector $\mathbf{R}_m$, indicating the primitive unit cell, in which the LWF is centered ($m = 0$ for the reference cell). The index i runs from 1 to N_b , the number of filled electron bands used for the localization procedure; the correlation calculation is restricted usually to valence bands LWFs. The latter are expressed as a linear combination of the Gaussian-type atomic orbitals (AOs) $\chi_\mu(\mathbf{r} - \mathbf{R}_n) = \chi_{\mu n}$ numbered by index $\mu = 1, \dots, M$ (M is the number of AOs in the reference cell) and the cell n translation vector $\mathbf{R}_n$:

$$W_{im}(\mathbf{r}) = \sum_{\mu n} l_{\mu n, im} \chi_{\mu n}(\mathbf{r}) \quad (5.92)$$

AOs constitute the nonorthogonal basis set used for the solution of the HF crystalline equations. To exploit the translation invariance property of LWFs, the matrix $L_{\mu n}^i = l_{\mu n, i0}$ has been introduced.

As in the molecular case (Sect. 5.1.5) for the virtual space, the projected AOs (PAOs) are used. To generate PAOs, the projector $\hat{P} = \sum_l^{\text{occ}} |l\rangle \langle l|$ onto the occupied HF space is expressed in terms of the density matrix in an AO representation, P , which is calculated very accurately by the CRYSTAL program via Brillouin-zone integration over all canonical occupied crystalline orbitals $|l\rangle$:

$$\hat{P} = \sum_{\mu\nu} |v\rangle P_{\mu\nu} \langle \mu| \quad (5.93)$$

The projector onto the virtual space is hence obtained: $\hat{Q} = 1 - \hat{P}$. By acting with $\hat{Q}$ on any one of the local functions $\chi_{\mu n} \equiv \chi_\beta$ of the original AO set, a Q-projected AO is obtained, or simply PAO:

$$\hat{Q} \chi_\beta(\mathbf{r}) = \sum_{\mu n} Q_{v\mu} \chi_{\mu n} = \tilde{\chi}_\beta(\mathbf{r}) \quad (5.94)$$

In what follows, PAOs are identified with the Latin letter corresponding to the Greek letter labeling the AOs from which they are generated, $\tilde{\chi}_\beta(\mathbf{r}) \leftrightarrow |b\rangle \equiv |bn\rangle$.

The set of all PAOs so generated (the standard PAO set) constitutes a nonorthogonal, linearly dependent, incomplete set of local functions, strictly orthogonal to all WFs. The problem of the adequacy of the standard set to describe excitations is a delicate issue, because the basis sets usually adopted to solve the HF problem for crystals are calibrated so as to describe accurately only the occupied subspace. Indications from molecular experience could not be easily transferable to the periodic case, especially in the case of dense crystals.

An essential feature of $O(N)$ local techniques is the introduction of some metric expressing the “distance” between local functions and the approximate treatment or total neglect of terms entering the exact equations, according to the distance between

the functions on which they depend. The wealth of experience gained in molecular studies can be exploited to this end.

A preliminary step is the definition of WF domains. According to the standard convention, the domain of the i th WF, $\mathbf{D}_i \equiv \{\chi_\alpha\}_i$ is the set of all AOs associated with the smallest and most compact set of atoms such that $\mathbf{D}_i$ “spans” W_i ; it is clearly sufficient to define this set for WFs in the reference cell ($im = i0$). The criterion adopted to select the spanning set is based on the one proposed by Boughton and Pulay [183]. Briefly, one includes in the set, step by step, all AOs belonging to a group of symmetry-equivalent atoms (i.e., atoms that are carried into each other by a symmetry operation that reproduces the LWF into itself). At each step, the norm N^{BP} of the difference between W_i and the best possible linear combination of AOs in the set is determined. The process is stopped when N^{BP} is below a certain threshold T^{BP} , for instance, 0.02; T^{BP} will be called the Boughton–Pulay (BP) parameter. The sequence according to which atoms are introduced in the domain is as follows. First, a “kernel” is selected including atoms A that contribute a Mulliken population Q_i^A larger than a certain threshold, *for example*, 0.2 ($Q_i^A = |\sum_{\beta \in A} \sum_{\alpha} P_{i,\beta}^n P_{i,\alpha}^n (vn|\mu m)|$; $\beta \equiv \nu m$); next, groups of symmetry-related atoms are introduced in order of increasing distance from the kernel (if the distance is the same, atoms with larger Q_i^A are included first).

After defining the domains, it is expedient to introduce, for any two WFs, i and j , a measure d_{ij} of the distance between them: the standard definition was adopted, namely, the minimum distance between any two atoms belonging to the respective kernels. A classification of LWF pairs by distance is then possible, based on the idea (strongly supported by the results of molecular calculations) that excitations from two local occupied orbitals become progressively less important with increasing distance d between the two centers. Strong ($d = 0$), weak ($0 < d \leq d_1$), distant ($d_1 < d < d_2$), and very distant ($d_2 < d$) pairs can be so termed, and the respective excitations are treated in a progressively less accurate way; in molecular calculations, a standard choice is $d_1 = 8$ Bohr, $d_2 = 15$ Bohr (see Sect. 5.1.5). The *total neglect* of contributions from very distant pairs is crucial to the realization of $O(N)$ computational schemes. In the following, two WFs will be said to be “close-by” each other if they do *not* form a very distant pair. For each WF pair, a pair-excitation domain or simply “pair domain” can be defined, which is the union of the respective domains ($\mathbf{D}_{i,j} \in \mathbf{D}_i \cup \mathbf{D}_j$). Given the biunivocal correspondence between AOs and PAOs (see (5.94)), $\tilde{\chi}_\beta$ will be said to “belong to” $\mathbf{D}_{ij}$ (briefly, $|b\rangle \in \mathbf{D}_{ij}$) if χ_β does. Excitations from i, j are usually restricted to PAOs belonging to $\mathbf{D}_{ij}$.

The use of distance criteria in the definition of the shape of the LWF domains and for controlling the level of the approximation is certainly not the only possibility, even if it is the simplest one; for instance, some “topological” index might be used instead, as is already possible in the MOLPRO program (<http://www.molpro.net>). Definitions and conventions introduced are not specific of any given level of local correlation theory and can be used both in CC and MP theory. In [103] the MP2, the simplest local correlation method, was considered.

The first-order perturbative correction to the HF wavefunction (5.37) is written as a combination of contravariant doubly excited configurations

$$|\Psi^{(1)}\rangle = \sum_{ij} |\Psi\rangle_{(ij)} \quad (5.95)$$

where

$$|\Psi\rangle_{(ij)} = \sum_{ab} T_{ab}^{ij} |\Phi_{ab}^{ij}\rangle \quad (5.96)$$

The exact equations that determine the excitation amplitudes T_{ab}^{ij} are

$$0 = R_{ab}^{ij} = K_{ab}^{ij} + \sum_{cd} \left\{ F_{ac} T_{cd}^{ij} S_{db} + S_{ac} T_{cd}^{ij} F_{db} - S_{ac} \left[\sum_l \left(F_{il} T_{cd}^{lj} + T_{cd}^{il} F_{lj} \right) \right] S_{db} \right\} \quad (5.97)$$

Here, K_{ab}^{ij} is the two-electron “exchange” integral

$$K_{ab}^{ij} = (ia|jb) \quad (5.98)$$

F_{il} and F_{db} are elements of the WF or PAO representation of the Fock operator, respectively, and S_{ab} is the overlap between PAOs. Equation (5.97) must be solved iteratively in the unknown amplitudes until all residuals R_{ab}^{ij} are zero. For any given set of amplitudes, the Hylleraas functional can be calculated:

$$E_2 = \sum_{(ij)} E_2^{ij} = \sum_{ij} \sum_{ab} (K_{ab}^{ij} + R_{ab}^{ij}) (2T_{ab}^{ij} - T_{ba}^{ij}) \quad (5.99)$$

It is easily shown that $E_2 \geq E^{(2)}$ (the MP2 estimate of the correlation energy), the equality sign holding true only at convergence, when all residuals are zero. In the above equations, the locality assumption is introduced according to the vicinity criteria, by restricting the sums over (ij) to close-by WF pairs and those over (ab) to PAOs $\in \mathbf{D}_{ij}$.

For the case of a crystalline application, the fact was used that all two-index quantities (Fock matrix in the PAO and in the WF representation, overlap matrix in the PAO representation) and all four-index quantities (amplitudes, residuals, two-electron integrals) are translationally invariant. For instance,

$$T_{an'+m,bm'+n}^{im,j(n+m)} = T_{an',bm'}^{0,jn} \quad (5.100)$$

Furthermore, the total correction energy can be written as a sum of *correction energies per cell*: $E_2 = L E_2^{\text{cell}}$, where L is the total number of cells in the crystal

with periodic boundary conditions, and the expression for E_2^{cell} is the same as in (5.99), but with the sum restricted to “zero-cell” WF pairs, that is, with the first WF in the reference zero cell:

$$E_2^{\text{cell}} = \sum_{ijn} E_2^{i0,jn}$$

So, finally, it is confined to a *local* problem, *in the vicinity of the zero cell*. The computation becomes $O(0)$ with respect to the size L of the macroscopic crystal and (asymptotically) $O(N)$ with respect to the size N of its unit cell.

In order to reformulate (5.97) for a given zero-cell WF pair $(i0, jn)$ in the periodic case, the following notation is introduced:

$$R_{ab} = K_{ab} + A_{ab} + B_{ab} \quad (5.101)$$

where $a, b \equiv |am\rangle, |bn\rangle$ and the apex $i0, jn$ is implicit in all four terms. This allows an “internal” contribution, A_{ab} (second and third terms in (5.97)), which depends on the amplitudes referring to the same $i0, jn$ pair, and an “external” B_{ab} contribution (last two terms in (5.97)), which depends on amplitudes involving other WF pairs, to be distinguished.

The most computationally demanding step in the implementation of the local MP2 method is the evaluation of the two-electron integrals $K_{12} = (i_1 a_1 | i_2 a_2)$. The straightforward solution is to express them as a linear combination of analytical K^A integrals over AOs, with coefficients depending on the four local functions. Other techniques are possible, however. In [147], the technique of fitted LWF for local electron correlation methods was suggested. A very promising one is the so-called density-fitting approximation [137]. Exchange integral K is obtained in terms of two-center repulsion integrals $J_{F_1 F_2}$ between two AO-like functions $F_1(\mathbf{r})$ and $F_2(\mathbf{r})$, after expressing each product distribution as a linear combination of a suitable set of “fitting functions” $F_n(\mathbf{r})$.

In the problem of the four-index transformation, from $\{K^A\}$ to $\{K\}$, advantage can be taken, as is customary in molecular calculations, of the fact that the same K^A is needed for many K integrals. When the involved LWF is sufficiently distant, the approximate multipolar evaluation of K integrals is used. For an efficient use of this technique, a number of parameters must be accurately calibrated: the distance between WFs beyond which the multipolar technique substitutes the exact one and the value of the parameter defining the truncation of the AO expansion of WFs and PAOs, according to the value of the coefficient or of the distance of the AO from the LWF center. The last two aspects are interrelated: almost negligible tails at very large distance may give enormous high-order multipoles, leading to unphysical values of the interaction.

The possibility to eliminate the WFs’ tails may have a significant impact on the efficiency of LMP2 methods. For these methods, the most expensive step is the evaluation and transformation of four-index two-electron integrals, where the computational cost is governed by the spatial extent of the AO support of the individual WFs. The details of the evaluation of these integrals can be found in [103].

To improve the efficiency of the local correlation methods in nonconducting crystals, the technique for constructing compact (fitted) WFs in AO basis sets was suggested [147]. Nevertheless, the results are general and can also be applied to other cases where the LCAO expansion of WFs is a critical issue.

5.4.2 *Fitted Wannier Functions for Periodic Local Correlation Methods*

Although WFs are spatially localized, the localization region can be relatively large. As an illustration, one can consider the case of diamond [147]. In the LCAO approximation, the WFs are represented by the AO expansion coefficients. The coefficients of the four translationally inequivalent WFs (which correspond to the four upper valence bands of the HF reference) larger (in absolute value) than a threshold of 10^{-4} comprise the atomic functions centered in as much as 435(!) unit cells. Such a wide extent of WFs makes accurate calculations, in particular, local MP2 calculations, for solids, computationally difficult.

The slow decay of WFs is often related to their mutual orthogonality, which gives rise to long-range oscillating tails, containing no physically relevant information. For quite some time now, the possibility to avoid these tails by sacrificing orthogonality has been discussed. Many important results concerning the localization properties of WFs and nonorthogonal localized orbitals (NOLO) (following most of the authors, we do not use the term “Wannier functions” for nonorthogonal localized functions) were obtained for the one-dimensional (1D) case, [184–187]. It was shown that in the 1D case, the spread of the NOLOs can be lower than that of the WFs and the term “ultralocalized” was introduced for NOLO [185]. The LCAO expansion of the WF $W_{i0}(\mathbf{r})$ is defined as

$$W_i(\mathbf{r}) = \sum_{\mu \mathbf{R}} C_{\mu \mathbf{R}, i} \chi_{\mu}(\mathbf{r} - \mathbf{R}) \equiv \sum_{\mu} C_{\mu i} \chi_{\mu}(\mathbf{r}) \quad (5.102)$$

where $\chi_{\mu}(\mathbf{r} - \mathbf{R})$ represents the atomic function centered in the $\mathbf{R}$ th unit cell, $C_{\mu \mathbf{R}, i}$ is the corresponding AO-WF coefficient, and index μ combines the indices μ and $\mathbf{R}$. Equation (5.102) defines WFs for the reference unit cell. In [147], it was suggested to maximize the variational functional that defines the Löwdin population of the given localized function on a set of atoms surrounding the center of the localization:

$$I_i^{\text{no}} = \sum_{i \in S_i^{(\text{loc})}} \left(C_{\mu i}^{(\text{no-Lw})} \right)^2 = \left(W_i^{(\text{no})} | \hat{P}_{S_i^{(\text{loc})}}^{(\text{LW})} | W_i^{(\text{no})} \right) \quad (5.103)$$

where $C_{\mu i}^{(\text{no-Lw})}$ are the expansion coefficients of the NOLO $W_i^{(\text{no})}(\mathbf{r})$ over the Löwdin-orthogonalized atomic basis-set functions $\phi_{\mu}^{(\text{LW})}(\mathbf{r})$

$$W_i^{(\text{no})}(\mathbf{r}) = \sum_{\mu} C_{\mu i}^{(\text{no-LW})} \phi_{\mu}^{(\text{LW})}(\mathbf{r}) \quad (5.104)$$

$$\phi_{\mu}^{(\text{LW})}(\mathbf{r}) = \sum_{\mu'} \left(S_{\mu'\mu}^{(\text{AO})} \right)^{-1/2} \phi_{\mu'}(\mathbf{r}) \quad (5.105)$$

Here, $S_{\mu'\mu}^{(\text{AO})}$ is the AO overlap matrix, and $\hat{P}_{S_i^{(\text{loc})}}^{(\text{LW})}$ is an operator projecting onto the space of the Löwdin-orthogonalized AOs from the given set of atoms:

$$\hat{P}_{S_i^{(\text{loc})}}^{(\text{LW})} = \sum_{\mu \in S_i^{(\text{loc})}} |\phi_{\mu}^{(\text{LW})}\rangle \langle \phi_{\mu}^{(\text{LW})}| \quad (5.106)$$

The set of atomic orbitals $S_i^{(\text{loc})}$ determines the region (or the set of atoms); the corresponding localized functions $W_i^{(\text{no})}(\mathbf{r})$ should concentrate within.

Maximization of the functional (5.103) with a constraint of normalization of the functions $W_i^{(\text{no})}(\mathbf{r})$ can be carried out by diagonalizing the matrix of the operator $\hat{P}_{S_i^{(\text{loc})}}^{(\text{LW})}$ (5.106). The eigenvector of this matrix, corresponding to the highest eigenvalue, holds the coefficients of the expansion (5.104), providing the most localized NOLO in the sense of the functional (5.103). The basis for this matrix could be formed by the Bloch functions of the occupied bands, WFs, or even atomic orbitals, projected onto the occupied space.

During generation of the nonorthogonal functions, one should not lose the rank of the space spanned by these functions (i.e., the linear independency of the functions should be kept). For the crystals of sufficiently high symmetry, the rank can be preserved automatically if the basis used for the variational procedure is symmetrized [188]. The localized functions are basis functions of irreducible representations (irreps) of the site groups related to the centroids of these functions [13]. Thus, if the basis for the functional (5.103) is symmetrized according to these site group and irrep, the centering site of the localized function cannot change [13, 188]. So, when the localized functions are centered on an isolated symmetry point, the symmetrization of the basis keeps the functions linearly independent. Moreover, even if the centroid of the localized function is not an isolated symmetry point (lies on the symmetry axis or in the symmetry plane), but the symmetry of the crystal is still high enough, the rank still may be kept by just taking symmetry into account. Yet, in this case, the latter is not guaranteed. If preservation of rank cannot be assured by applying symmetry, one may have to apply some additional constraints—for example, as suggested in [189], the constraint of the nonsingularity for the localized functions overlap matrix or in [190], the constraint of freezing the centroids of the localized functions. However, the latter constraint might collide with the requirement of higher localization if the centers of the functions are not fixed by the symmetry.

The variational procedure should be performed in the space of the first vectors of the corresponding irreps. In other words, only symmetry-unique localized functions are to be obtained variationally. The remaining functions can be generated by applying the appropriate symmetry operators [13, 188]. If there is more than one

independent set of localized functions centered on the same site and transforming according to the same irrep, one can obtain all of them in the variational procedure either by taking the eigenfunctions of the diagonalized matrix corresponding to several of the highest eigenvalues instead of just one or by performing independent procedures for their generation. In the latter case, the variational procedure should be run in the WF-basis, and only one out of several WFs with the considered symmetry, which are centered on the same site, should be included in this basis. The symmetry properties of the WFs and localized functions can be determined in high-symmetry cases without the actual construction of WFs, by analyzing the symmetry of the Bloch functions corresponding to the valence bands. The symmetry information on the NOLOs (the site groups of the WF centroids and the irreps of the site groups) can be extracted using the induced representation theory. Let the symmetry of the WFs be defined unambiguously by the symmetry of Bloch states forming the occupied crystalline orbitals. For example, as was seen in Chap. 3, the four upper valence-band Bloch states in diamond-type crystals are connected with four WFs centered at the center of the atom–atom bond with the site-symmetry group D_{3d} and transforming over the one-dimensional a_{1g} -irrep of this group. The coset representatives in the decomposition of space group O_h^7 in cosets over subgroup D_{3d} transform this WF into another three equivalent WFs directed along the interatomic bonds. In MgO crystal, four upper valence bands, nondegenerated and triple degenerated, correspond to four WFs centered at the oxygen site (site-symmetry group O_h coincides with the point group of a crystal) and transforming over irreps a_{1g} and t_{1u} of O_h group. This is the case when NOLOs different by symmetry are centered at the same atom.

In low-symmetry cases, one needs to know also the centering points of the initial orthogonal symmetry-adapted WFs. Let instead of the diamond structure one consider ZnS (sphalerite) structure. The centering of four WFs corresponding to four upper valence bands is defined by symmetry as C_{3v} , *that is*, WFs centers are at the atom–atom bond. The actual centering cannot be found only from symmetry considerations. In this case, the additional information is necessary to fix the WFs centers. One possibility is to use the nonsymmetry-adapted WFs generated by CRYSTAL code [21] and a posteriori to apply the technique of Casassa et al. [191] to nonsymmetrized WFs. This technique is considered in the next section. If the WFs' centers are not fixed, the method under consideration can give highly localized but linearly dependent functions, which of course are of no use. In some special low-symmetry cases, when there are several independent WFs of the same symmetry (like s - and p_z -WFs of oxygen in rutile structure TiO_2), the method also requires the orthogonal WFs themselves to use them as a basis for construction of NOLOs. In other cases, one can also use Bloch functions as such a basis.

Let the symmetry-adapted localized orthogonal WF be constructed and used furthermore in the post-Hartree–Fock calculations. In numerical local MP2 calculations, the sum (5.102) has to be truncated according to some threshold. It is possible to make a truncation based on the magnitude of the calculated WFs coefficients in this sum. In effect, all contributions due to WF coefficients below some threshold could be disregarded. Unfortunately, only relatively loose thresholds can presently

be afforded in practical calculations [103], and the numbers of translation vectors $\mathbf{R}$ taken into account may become a critical parameter significantly influencing the accuracy of the calculation. For example, the four-index transformation of the two-electron integrals in the CRYSCOR computer code (<http://www.theochem.unito.it/lcc2004/cryscor.pdf>) uses tolerances for the LCAO coefficients of the WFs of 10^{-2} – 10^{-3} . Such loose thresholds can hardly guarantee sufficient accuracy for reliable results, yet tighter thresholds render the calculations too expensive.

In order to treat the truncation of the WFs' tails in an improved way, the fitting of WFs was suggested [147]. The localization criterion is introduced:

$$I_i^{(\text{fit})} = \int (\tilde{W}_i(\mathbf{r}) - W_i(\mathbf{r}))^2 d\mathbf{r} \quad (5.107)$$

where the function $\tilde{W}_i(\mathbf{r})$ is the truncated (fitted) localized function

$$\tilde{W}_i(\mathbf{r}) = \sum_{\mu \in S_i^{(\text{fit})}} C_{\mu i} \phi_{\mu}(\mathbf{r}) \quad (5.108)$$

The sum (5.108) differs from the infinite sum (5.102) because the summation is made over $S_i^{(\text{fit})}$ containing an incomplete set of atomic functions centered only on atoms, which are in a way close to the centroid of the WF $W_i(\mathbf{r})$. The criterion (5.107) is utilized to *fit* the WF spanned by the basis functions within $S_i^{(\text{fit})}$ (the WF-AO fit domain) in a least-squares sense with respect to the untruncated function. Hence, minimizing the functional (5.107), the fitted WFs are

$$\tilde{W}_i^{(\text{fit})}(\mathbf{r}) = \sum_{\mu \in S_i^{(\text{fit})}} C_{\mu i}^{(\text{fit})} \phi_{\mu}(\mathbf{r}) \quad (5.109)$$

with the fitted coefficients $C_{\mu i}^{(\text{fit})}$, obtained by solving the linear equations

$$\sum_{\mu' \in S_i^{(\text{fit})}} S_{\mu' \mu}^{(\text{AO})} C_{\mu' i}^{(\text{fit})} = \sum_{\mu'} S_{\mu' \mu}^{(\text{AO})} C_{\mu' i} \quad (5.110)$$

The fitting according to (5.110) is formally equivalent to other fitting techniques like density fitting [137, 138], with the AOs from the WF-AO fit domain in the role of the auxiliary basis functions.

By successively adding coordination spheres of atoms and thus their atomic functions to the set $S_i^{(\text{fit})}$ and refitting the coefficients $C_{\mu' i}^{(\text{fit})}$, one can finally obtain the fitted WF $\tilde{W}_i^{(\text{fit})}(\mathbf{r})$ that to a given tolerance, approximates the exact WF $W_i(\mathbf{r})$. Within a chosen tolerance, the number of atoms contributing significantly to the fitted WFs $\tilde{W}_i^{(\text{fit})}(\mathbf{r})$ is essentially smaller than that of the functions $\tilde{W}_i(\mathbf{r})$.

The fitting procedure can be applied also to the NOLOs, once they are constructed. The localization-fitting process for the NOLOs is most efficient when the set of atomic orbitals and WF-AO fit domain $S_i^{(\text{fit})}$ at both stages are chosen to be the same. Indeed, small values of the fitting functional $I_i^{(\text{fit})}$ can be expected if all

the sites with a relatively large value of the NOLO are included in the corresponding WF-AO fit domain. Thus, it does not make sense to use domains $S_i^{(\text{fit})}$ smaller than $S_i^{(\text{loc})}$, since the latter guarantees small values for localized functions only outside its region. On the other hand, if the value for the fitting functional within the chosen WF-AO fit domain is not sufficiently small, it is more efficient, when one does not just enlarge it (as in the case of WFs) but recalculates beforehand the reference NOLOs with the new set $S_i^{(\text{loc})}$ enlarged accordingly. Actually, only the LCAO coefficients of the NOLO (or WFs) $C_{\mu i}$ can be refitted by minimizing the functional (5.107). The Löwdin coefficients cannot be modified by the fitting (5.110), since the corresponding AO overlap matrix involved is the identity matrix. This means that the Löwdin coefficients within the WF-AO fit domain are optimal with respect to the functional (5.107) providing its minimum. For orthogonal atomic-like basis sets (such as Löwdin-orthogonalized AOs), the fitting process just corresponds to the truncation of the WF coefficients according to the chosen WF-AO fit domain. Constructing the NOLO in the case of orthogonal basis sets might be more efficient, since the localization functional (5.103) addresses the coefficients relative to the orthogonalized basis-set functions directly. The efficiency of the fitting procedure for the localized functions depends on redundancies carried in the corresponding basis sets, which are large in the case of highly overlapping basis sets. Summarizing the above, the method for obtaining ultralocalized nonorthogonal fitted functions implies the following. Once the symmetry of the localized orbitals has been determined, for every symmetry-unique function the variational procedure in the symmetrized basis according to the functional (5.103) is performed, followed by generating the fitted functions with limited support from the former by solving (5.110). The sets of the atomic orbitals $S_i^{(\text{loc})}$ and $S_i^{(\text{fit})}$ in these two steps are to be taken as the same. If the value of the fitting functional (5.107) does not drop below a predefined threshold, a new star of atoms is added and the process is repeated.

The atomic functions projected onto the orthogonal complement of the occupied space (PAOs), which represent in the framework of local correlation methods the virtual states (see Sect. 5.4.1), are also localized functions. Therefore, similar techniques could also be used to restrict the spatial extent of these PAOs. However, since PAOs are to be constructed by projecting out the space spanned by the *fitted* WFs or NOLOs (rather than the untruncated parental WFs or NOLOs), one can anticipate that PAOs will automatically possess a limited support, determined basically by the WF-AO fit domains.

The efficiency of the method suggested was demonstrated in diamond crystal local MP2 calculations [147]. Since in the present version of the CRYSCOR code (<http://www.theochem.unito.it/lcc2004/cryscor.pdf>) a possible nonorthogonality of the localized functions representing the occupied manifold is not taken into account, the local MP2 energy in diamond has been calculated using only orthogonal WFs with and without fitting. The weak- and distant-pair distances were set to 2 Å. The threshold for PAOs coefficients was set to 10^{-2} . Only the coefficients for the AOs from the first three stars of atoms were included in the transformation of the 4-index integrals (WF fitting was also performed within the first three stars of atoms). Local MP2 correlation energy and timings were then compared with the

corresponding values of a reference calculation, which were obtained by employing quite a low screening threshold of 5×10^{-4} for the WF coefficients (smaller thresholds are hardly manageable, presently [103]). Evidently, the fitting of WF coefficients can improve the accuracy and/or reduce the computational cost of the local MP2 calculations for solids. The results of these calculations show: if fitted WFs are used, the estimate of the error in the calculated MP2 energy (the difference between the calculated and reference energies) becomes substantially smaller, while the CPU time of the calculation remains about the same.

5.4.3 *Symmetry Exploitation in Local MP2 Method for Periodic Systems*

In local MP2 calculations of solids, it is important to exploit the point symmetry, in order to confine calculations to an irreducible subset; savings of computer time and storage can be substantial in a number of cases of importance. As was discussed in the preceding subsection, the WFs symmetry can be taken into account on the step of WFs generation using the theory of induced representations of space groups and symmetry information about the Bloch states involved in the WFs generation. However, there is another possibility—a symmetrization of a set of constructed LWF before starting the local MP2 calculations. A set of LWF is a posteriori symmetrized, and symmetry-adapted localized WFs (SALWF) are constructed. A rapid account of this technique was given in [103], while a more detailed analysis can be found in [191].

SALWFs are partitioned into subsets (f) belonging to a class b , each transforming into itself under the operators of a local symmetry point-subgroup F_f of the full point group F , while the operations of the associated left- or right-cosets transform subset f into another equivalent one in the same class. As an example, in the diamond crystal case ($F = O_h$), subset f consists of one LWF centered in the middle of the atom–atom bond ($F_f = D_{3d}$). The LWFs class consists of four LWFs describing the upper valence band of four subbands. Formally, the symmetrization and the localization procedures are in principle independent: for a chosen localization criteria, the LWFs symmetrized before construction have to be close to those symmetrized a posteriori their construction. In fact, the real localization of electron density may be sufficiently complicated. In a posteriori symmetrization, the choice of F_f is generally not unique (in the simple case of diamond, it was unique), and two possible cases may be mentioned: (a) the subsets are chosen so as to minimize the order of F_f and (b) F_f is chosen so that the representation of its elements in the SALWF basis set is maximally factorized according to the irreducible representations of F_f . Functions optimally localized under a given criterion may feature both properties (as is the case when a regular representation is possible), any one of them, or none of them [191]. For example, let us consider four nonsymmetrized LWFs defined by Bloch states of four upper valence bands in MgO crystal (the valence electron pairs related to the anions are supposed to be localized according to the Boys criterion [36]). In that situation, the

localization criterion is just compatible with an sp^3 hybridization but, as the local point-symmetry group of the atom is cubic and not tetrahedral, the set of orbitals is constrained to form a reducible representation of O_h with no privileged orientation. The LWFs fall into a situation not described by the previously mentioned cases. A similar behavior is displayed by “banana” orbitals in triple bonds or core electrons in a variety of highly symmetric crystals.

For the scope of numerical applications, even in those cases where localization gives rise to definite symmetry properties (as in the diamond case), accurate symmetry equivalences are only reached under strong numerical conditions in the localization algorithm. This can be, in several cases, very computationally demanding, and a more efficient shortcut to obtain accurate symmetry equivalence together with a good localization character is therefore desirable.

Due to the previously mentioned difficulties of an a priori prediction of what kind of symmetry behavior will be compatible with good localization properties under efficient criteria, in [191], an a posteriori strategy was adopted based on a “chemical” analysis of the problem, which is made easier by the fact that WFs are expressed as a linear combination of atomic orbitals (AOs); it represents a compromise between the two criteria previously mentioned. Starting from a set of localized WFs, the main steps of the presented scheme are:

- (1) Recognize if classes of symmetry-related single-WF subsets already exist.
- (2) Classify the remaining WFs, if possible, into atomic or bond WFs, according to the Mulliken population analysis. The extension to periodic systems of Mulliken population analysis introduced for molecules is considered in Chap. 9. The electron density of LWF W_{i0} is partitioned into atomic populations Q_{AM}^i , assigned to different atoms in the primitive cells M . One can preclassify W_{i0} as:
 - (a) Atomic LWF: an atom AM exists for which $Q_{AM} > 0.9$. This category includes “core” LWFs but also LWFs associated with valence AOs in anions of very ionic systems. “Lone pair” or “hydrogen-bond” LWFs may also enter this category.
 - (b) Bond LWF: two near-by atoms AM, BN exist such that $Q_{AM}^i + Q_{BN}^i \geq 0.9$, and the ratio Q_{AM}^i / Q_{BN}^i is comprised between 1 (pure covalency) and 1/4 (high ionicity).
 - (c) Atypical LWF: W_{i0} does not enter the previous categories.
- (3) Using the previous information, recognize the subsets, the site-symmetry subgroups F_f , and the irreducible representations to which they belong.
- (4) Generate and orthonormalize the new SALWFs.

A criterion based on a Mulliken analysis is adopted again to subdivide atomic LWFs associated to the same irreducible atom A into shell-subsets (without loss of generality, A can be assumed to be in reference 0 cell). The bond LWFs are the representatives of double and triple bonds and are assigned to the $(AO - BM)$ -subset. Thus, part of the LWFs, classified as SALWFs, only require numerical

refinement or the subset including all the atypical ones. All others are grouped in subsets S , either of a “shell” or of a “bond” type, each one comprising ns members.

Bond and atomic LWFs are characterized by one and two atomic centers, respectively. Using this information, the subgroup G_f that leaves invariant the corresponding symmetry element (either a center or an axis in real space) is found. The irreducible representations of G_f are found, and for each of them, the representative matrices are first constructed and, then, used to build up the idempotent projector operators for the first row and the shift operators for all other rows. The details of this procedure can be found in [191, 192].

Finally, when all atomic and bond subsets have been symmetry adapted, they are orthonormalized. Orthonormalization is performed in two steps. Using a given net in reciprocal space, the nonorthogonal functions generated in the previously described steps are transformed into Bloch functions, orthonormalized using a Löwdin scheme in each $\mathbf{k}$ -point of the net and backtransformed into Wannier functions. This is accomplished using a straightforward modification of the Wannierization scheme reported in [193]. At this step, the resulting SALWFs are orthonormal just under Born–Von Karman cyclic conditions. If necessary, the functions can be corrected to satisfy accurate orthonormalization by integration over the whole real space. We discussed a method [191] for generating from a set of (generally nonsymmetric) localized Wannier functions (LWF), an equivalent set of orthonormal functions that are adapted not only to the translational but also to the point symmetry of the crystalline structure while maintaining good locality features. They are called therefore SALWFs (symmetry-adapted localized Wannier functions). At variance with other methods based on the induced representations theory, this method is largely based on a chemical analysis of the structure of LWFs: despite this somewhat empirical character, it performs very well with a variety of molecular and crystalline systems.

The effectiveness of this procedure was demonstrated [191] by way of examples, with reference to four test cases: the CH_3Cl molecule (with C_{3v} symmetry), linear polyacetylene, lithium bromide with the rocksalt structure (symmorphic space group O_h^5), and crystalline silicon (nonsymmorphic space group O_h^7). SALWFs generated appear well suited for use in the local correlation methods. In the future, the symmetrized fitted LWFs can be used to have a more efficient computational procedure of LMP2 calculations.

Concluding the consideration of the modern electron correlation methods for periodic systems, we see that the first-principles LCAO post-HF methods for solids are essentially more difficult compared with those for the molecular systems. This is why until now, the simpler semiempirical approaches have been popular for crystals. These approaches allow the intra-atomic and partly interatomic correlation effects to be taken into account by introduction of semiempirical parameters calibrated on the basis of first-principles calculations or experimental data. In many cases, these methods give correct qualitative characteristics of the crystalline electronic structure that may be later corrected in the first-principles calculations.

The semiempirical LCAO methods for periodic systems are considered in the next chapter.

Chapter 6

Semiempirical LCAO Methods for Molecules and Periodic Systems

The limitations of the first-principles HF LCAO calculations of the periodic systems are caused mainly by the necessity to evaluate of multicenter two-electron integrals whose number grows proportionally as N^4 (N is the number of AOs used). Modern electron correlation methods for periodic systems are essentially more difficult compared with those for the molecular systems. For both these reasons, simpler semiempirical approaches have been popular for crystals until now. These approaches allow the intra-atomic and partly interatomic correlation effects to be taken into account by the introduction of semiempirical parameters calibrated on the basis of first-principles calculations or experimental data. In many cases, these methods give correct qualitative characteristics of the crystalline electronic structure that can be later corrected with the first-principles calculations. We discuss the extension of the LCAO empirical methods of molecular quantum chemistry (the Hückel theory and the method of Mulliken–Rüdenberg) to periodic systems. In particular, we consider the extension of the *semiempirical* ZDO (zero differential overlap) methods which are based on the simplification of the HF LCAO Hamiltonian and require iterative (self-consistent) density matrix calculations: the complete, intermediate, and modified neglect of the differential overlap (CNDO, INDO, MNDO—approximations), the neglect of the diatomic differential overlap (NDDO), and others, using the neglect of differential overlap (NDO) or modified NDO (MNDO) approximations. The cyclic-cluster model is analyzed. In cyclic-cluster calculations, one returns to the molecular level without the loss of symmetry, replacing a whole crystal by one supercell (multiple of the primitive unit cell), applying to it periodic boundary conditions (PBC), and embedding a cyclic cluster in the Madelung field of the surrounding crystal. Instead of the system of coupled LCAO equations for different wavevectors in the BZ, one has one equation to be solved in each iteration as in the case of molecules. PBC introduction for the cyclic cluster chosen allows one to establish the symmetry connection between the cyclic-cluster molecular orbitals and some crystalline orbitals of a whole crystal. The implementation of the cyclic-cluster model in MSINDO (modified spectroscopic INDO) and Hartree–Fock LCAO methods is considered. It is shown for the rutile

crystal as an example that this approach gives reasonable agreement with the results of periodic calculations and at the same time is essentially simpler in terms of its practical realization.

6.1 Extended Hückel and Mulliken–Rüdenberg Approximations

6.1.1 *Nonself-Consistent Extended Hückel–Tight-Binding Method*

During the early days of molecular quantum chemistry, when computational power was minimal, the semiempirical LCAO methods were applied even for small molecules [194, 195]. Later, at the beginning of the 1970s, these approaches were extended to crystalline solids [196–198] and allowed calculations of their properties to be made in the period when the first-principles HF LCAO calculations for solids were practically unreliable. The limitations of the first-principles HF LCAO calculations are caused mainly by the necessity of evaluation of multicenter two-electron integrals whose number grows proportionally as N^4 (N is the number of AOs used). Therefore, in the quantum chemistry of large molecules and solids, the semiempirical calculations continue to appear in large numbers in chemical literature. We refer the reader to the recently published book [97], Chap. 5, where the corresponding bibliography of semiempirical methods for molecules can be found.

In this chapter we discuss the extension of LCAO semiempirical methods of molecular quantum chemistry to periodic systems and provide a comparison between semiempirical Hamiltonians for molecules and crystals.

The approximate LCAO methods of quantum chemistry can be divided on empirical (semiquantitative) and semiempirical grounds.

The *empirical (semiquantitative)* methods are based on a one-electron effective Hamiltonian and may be considered as partly intuitive: extended Hückel theory (EHT) for molecules [194] and its counterpart for periodic systems—the tight-binding (TB) approximation. As, in these methods, the effective Hamiltonian is postulated, there is no necessity to make iterative (self-consistent) calculations. Some modifications of the EHT method introduce the self-consistent charge-configuration calculations of the effective Hamiltonian and are known as the method of Mulliken–Rüdenberg [199].

The *semiempirical* methods are based on the simplification of the HF LCAO Hamiltonian and require the iterative (self-consistent) density matrix calculations: complete and intermediate neglect of differential overlap (CNDO and INDO—approximations), neglect of diatomic differential overlap (NDDO), and others, using the neglect of differential overlap (NDO) approximation.

Both groups of methods use the valence-electron approximation, *for example*, all core electrons are ignored. It is assumed that core electrons are sufficiently

invariant to differing chemical environments so that changes in their orbitals as a function of environment are of no chemical consequence, energetic, or otherwise. The valence atomic orbitals are represented by a so-called Slater-type orbital (STO). The mathematical form of a normalized STO (in atom-centered polar coordinates) is

$$\chi_{\mu}(\mathbf{r}) = R_{\mu}(r)Y_{lm}(\theta, \varphi) = N_{\mu}r^{n-1}\exp(-\zeta_{\mu}r)Y_{lm}(\theta, \varphi) \quad (6.1)$$

The radial part $R_{\mu}(r)$ of STO $\chi_{\mu}(\mathbf{r})$ depends on n (the principal quantum number for the valence orbital) and an orbital exponent ζ_{μ} that can be chosen according to a simple set of rules developed by Slater [200] (see Sect. 8.1.1) in EHT and TB methods or considered as semiempirical parameters. The angular parts are spherical harmonic functions $Y_{lm}(\theta, \varphi)$ depending on the angular momentum quantum numbers l and m (in the majority of cases their real combinations $Y_{lm}(\theta, \varphi) \pm Y_{l-m}(\theta, \varphi)$ are used, giving for $l = 1, 2, 3$ the angular part of p, d, f atomic functions, respectively). STOs have a number of features that make them attractive. The orbital has the correct exponential decay with increasing r , the angular component is hydrogen-like, and the $1s$ orbital has, as it should, a cusp at the nucleus (i.e., is not smooth). More importantly, from a practical point of view, overlap integrals between two STOs as a function of interatomic distance are readily computed. In simple Extended Hückel theory (EHT), all STOs in a molecule are supposed to be orthogonal; in EHT, the AOs overlap matrix S is computed directly.

In EHT for molecules, the MOs and the corresponding one-electron energies are found as the eigenfunctions and eigenvalues of the effective Hamiltonian H :

$$\det |H_{\mu\nu} - S_{\mu\nu}\epsilon_i| = 0 \quad (6.2)$$

The dimension of the matrices H and S is equal to the whole number of the atomic STOs.

The values for diagonal elements $H_{\mu\mu}$ are taken as the negative of the average ionization potential for an electron in the appropriate valence orbital. Of course in many-electron atoms, the valence-state ionization potential (VSIP) for the ground-state atomic term may not necessarily be the best choice for the atom in a molecule, so this term is best regarded as an adjustable parameter, although one with a clear, physical basis. VSIPs have been tabulated for most of the atoms in the periodic table [201, 202].

The nondiagonal elements (for the nearest neighbors known as resonance integrals) are more difficult to approximate. Wolfsberg and Helmholz [203] suggested the following convention:

$$H_{\mu\nu} = \frac{K}{2} (H_{\mu\mu} + H_{\nu\nu}) S_{\mu\nu} \quad (6.3)$$

where K is an empirical constant and $S_{\mu\nu}$ is the overlap integral. Thus, the energy associated with the matrix element is proportional to the average of the VSIPs for the

two orbitals μ and ν times the extent to which the two orbitals overlap in space (note that, by symmetry of angular parts, the overlap between different valence STOs on the same atom is zero). Originally, the constant K was given a different value for matrix elements corresponding to σ - and π -type bonding interactions. In modern EHT calculations, it is typically taken as 1.75 for *all* matrix elements, although it can still be viewed as an adjustable parameter when such adjustment is warranted.

Because the matrix elements do not depend on the final MOs in any way (unlike HF theory), the process is not iterative, so it is very fast, even for very large molecules.

The very approximate nature of the resonance integrals in EHT makes it inaccurate for the calculation of the atomic positions in molecules so that use of EHT is best restricted to systems for which experimental geometries are available. For such cases, EHT tends to be used today to generate qualitatively correct MOs in much the same fashion as it was used 50 years ago [97]. In the twenty-first century, such a molecular problem has become amenable to more accurate treatments (HF and post-HF methods, see Chaps. 4 and 5), so the province of EHT is now primarily very large systems, like extended solids, where its speed makes it a practical option for understanding the band structure of bulk and surface states [204].

In the EHT method for solids, crystalline orbitals (4.55) are expanded over the Bloch sums (4.53) of valence AOs, and the secular equation

$$\det |H_{\mu\nu}(\mathbf{k}) - S_{\mu\nu}(\mathbf{k})\epsilon_i(\mathbf{k})| = 0 \quad (6.4)$$

is solved where $H_{\mu\nu}(\mathbf{k})$ and $S_{\mu\nu}(\mathbf{k})$ are, respectively, the matrix elements of the effective one-electron Hamiltonian and of the overlap integrals between two LCAO Bloch sums expressed as

$$H_{\mu\nu}(\mathbf{k}) = \sum_{\mathbf{R}_n} \exp(i\mathbf{k} \cdot \mathbf{R}_n) H_{\mu\nu}(\mathbf{r} - \mathbf{R}_n), \quad S_{\mu\nu}(\mathbf{k}) = \sum_{\mathbf{R}_n} \exp(i\mathbf{k} \cdot \mathbf{R}_n) S_{\mu\nu}(\mathbf{r} - \mathbf{R}_n) \quad (6.5)$$

The difference between the matrix elements $H_{\mu\nu}(\mathbf{k})$ (6.5) and $F_{\mu\nu}(\mathbf{k})$ (4.56) is due to the difference between HF and EHT Hamiltonians: the former includes one-electron and two-electron parts and depends on the crystalline density matrix (4.65), while the latter are assumed to be proportional to the overlap matrix elements. The explicit form of $H_{\mu\nu}(\mathbf{r} - \mathbf{R}_n)$ is given as follows:

$$H_{\mu\nu}(\mathbf{r} - \mathbf{R}_n) = \frac{1}{2} K_{\mu\nu} (H_{\mu\mu} + H_{\nu\nu}) S_{\mu\nu}(\mathbf{r} - \mathbf{R}_n) \quad (6.6)$$

where the proportionality constant $K_{\mu\nu} = 1$ for $\mu = \nu$ and otherwise $K_{\mu\nu}$ is an empirically adjustable parameter, $H_{\mu\nu}$ is the valence-state ionization potential (VSIP) of AO χ_μ . These matrix elements are fixed at the beginning of EHT calculations so that the secular equations (6.4) are solved independently for different wavevector $\mathbf{k}$ values and the calculation does not require the self-consistency. Due to the translation symmetry, the order of secular equation (6.4) is equal to the number

Table 6.1 Fitted parameters for Si crystal, [204]

Si	Neighbors					
	1	2	3	4	5	6
K_{ss}	1.403	1.523	0.955	1.355	5.450	4.550
$K_{sp\sigma}$	1.409	1.931	2.095	0.375	2.485	0.000
$K_{pp\sigma}$	1.890	3.050	3.780	1.750	0.000	1.800
$K_{pp\pi}$	2.290	2.570	0.150	2.150	1.000	4.500

of valence AOs per primitive cell. The field of lattice summations in matrix elements $H_{\mu\nu}(\mathbf{k})$, $S_{\mu\nu}(\mathbf{k})$ depends on the model chosen. In the infinite-crystal model, the summations are made up to the distance when the overlap integrals $S_{\mu\nu}(\mathbf{r} - \mathbf{R}_n)$ become less than some threshold. In the cyclic-cluster model, these summations are made in such a way that the lattice summation is restricted by the cyclic-cluster translation vector. As was already mentioned, the shape and size of the cyclic cluster chosen define the $\mathbf{k}$ -vectors set, for which the calculation is in fact made. As EHT is a nonself-consistent method (the matrix elements are calculated independently for different $\mathbf{k}$ -vectors), the choice of one or another restriction for summation in the direct lattice is mainly a conceptual point. The EHT approach to solids (known also as the tight-binding (TB) approximation) is applied in many cases as an interpolation method, to be used in connection with more accurate calculation schemes or experimental data [56]. As an example, we consider the EHT band structure of Si crystal, fitted in [204] to reproduce the experimental bandgap and optical properties. The lattice summation was taken over all atoms within the sixth-nearest neighbors. In order to reproduce optical properties, it turned out that four proportionality constants (K_{ss} , $K_{sp\sigma}$, $K_{pp\sigma}$, and $K_{pp\pi}$) are required for each shell of neighbors resulting in 24 fitting parameters. Adding the ionization potentials I_s , I_p and orbital exponents ζ_s , ζ_p for the Slater-type AOs (which are also treated as fitting parameters), this amounts to a total 28 adjustable fitting parameters. These parameters have been determined by fitting to the pseudopotential band-structure calculations for the experimental value of the cubic lattice constant [205] and experimental data. The best-fit parameters are listed in Table 6.1.

In fitting the bands, special weight has been given to the valence and conduction bands at Γ , the conduction bands at L and K , and the conduction-band minima at $+0.85(2\pi/a_0)$ along the (001) directions, which may influence the optical properties. These band states are somewhat sensitive to the change in the individual values of the fitting parameters, and special attention has been paid to their determination. The energy eigenvalues at high-symmetry points of the BZ (see Fig. 3.2) are compared to the Hartree–Fock LCAO calculation and experimental values in Table 6.2.

The energies in eV are measured relative to the top of the valence band with the symmetry Γ_{5+} . As is seen from Table 6.2, an excellent description of the valence and conduction bands has been achieved throughout the Brillouin zone. The main features of the bands are reproduced quite accurately. More specifically, the highest valence and lowest conduction bands run parallel along the Λ , Δ , and Σ lines, and

Table 6.2 EHT fitted, HF, and experimental eigenvalues (in eV) for Si crystal at Γ , X, and L-points relative to the valence-band maxima

Level	Fitted	HF	Experimental
Γ	0.00	0.00	
Γ	-12.32	-12.36	-12.4, -12.5
Γ	3.43	3.43	3.45, 3.41
Γ	4.08	4.10	4.15
L	-10.82	-9.55	-9.3
L	-6.20	-6.96	-6.4, -6.8
L	-1.12	-1.23	-1.2
L	2.26	2.23	2.2, 2.3
L	4.43	4.34	3.9
X	-7.92	-7.69	
X	-2.95	-2.86	-2.5, -2.9
X	1.33	1.17	
Δ	1.13	1.10	1.13
K	1.62	1.66	

the indirect bandgap of Si, the Δ minima of which lie at 85% of the way along the $\Gamma - X$ directions, has been exactly reproduced. It is seen from Table 6.1 that the fitted values of EHT parameters are essentially different compared to those used for molecules. The orbital exponent value $\zeta_s = \zeta_p = 1.385$ found with Slater rules differs from the fitted values $\zeta_s = 1.656$, $\zeta_p = 1.728$. The neutral Si atom ionization potentials $I_s = 16.34$ eV, $I_p = 8.15$ eV also differ from the corresponding fitted values 15.55 eV and 7.62 eV, respectively. Analyzing the data given in Table 6.1, one sees that the proportionality constant is not the same for $2s$ and $2p$ orbitals (its value, 1.75, is taken in molecular calculations) and essentially depends on the interatomic distance. The fitted EHT parameters were used in [204] for the EHT calculations to study the molecular oxygen chemisorption and hydrogen-terminated Si(001) ultrathin films. Even when using modern computer codes and facilities, the first-principles calculations would be, in this case, very complicated as is seen from the examples given in Chap. 11. In the example considered, the remarkable fit for Si crystal has been achieved within the EHT formalism by defining a rather large parameter basis set that resembled a typical Slater–Koster (tight-binding) parametrization. However, it is surprising that, to our knowledge, a systematic quantitative study on the accuracy attainable with the EHT when applied to different bulk materials has been attempted only recently [206]. It was shown how the simple EHT method can be easily parameterized in order to yield accurate band structures for bulk materials, while the resulting optimized atomic orbital basis sets present good transferability properties. The number of parameters involved is exceedingly small, typically ten or eleven per structural phase. A new EHT parametrization scheme was applied to almost fifty elemental and compound bulk phases. An orthonormal AO basis set was chosen for each inequivalent atom M . Generally, the basis involves rather extended radial wavefunctions, although any other type of basis set may be employed as well. In this work, the Hamiltonian matrix elements $H_{\mu M, \nu N}$ were taken in the form:

$$H_{\mu M, \nu N} = K_{\text{EHT}} (I_{\mu M} + I_{\nu N}) / 2 \quad (6.7)$$

where K_{EHT} is a constant traditionally set to a value of 1.75 and $I_{\mu M}, I_{\nu N}$ are onsite energies of both elements M, N . From the above formula, it follows that the strength of the Hamiltonian matrix elements is weighted by the mean value of the onsite energies so that a shift in energy of these onsite parameters does not translate into a rigid shift in energy of the EHT-derived band structure. Therefore, and in order to avoid any arbitrariness in the origin of the energy scales, the Fermi level for transition metals to -10 eV was fixed and the top of the valence band for semiconductors at -13 eV. It was then found that increasing K_{EHT} to 2.3 consistently provided better fits for all elements, although similar good fits may be obtained with $K_{\text{EHT}} = 1.75$ if the Fermi level is lowered to around -20 eV. A minimal *spd* basis set per element was employed, while each AO is described by a double Slater wavefunction. Apart from the onsite energies (I_s, I_p , and I_d), this leads to three parameters per l quantum number: the exponents ζ_1 and ζ_2 (with $\zeta_1 < \zeta_2$) and the coefficient for the former, C_1 . The second coefficient C_2 is determined by imposing normalization of the wavefunction. For transition metals, the optimization of the three AO parameters was found to be redundant for the s and p orbitals, and equally good fits could be obtained by fixing ζ_2 to a rather large value: $\zeta_2 > 20.0$. Since such a highly localized term gives a negligible contribution to the overlaps with neighboring orbitals, it was explicitly omitted, while allowing the coefficient C_1 to take values smaller than 1.0 (i.e., the ζ_2 Slater orbital only contributes to the normalization of the wavefunction). For the d orbitals, on the contrary, it was found necessary to include the ζ_2 contribution. Hence, the transition-metal fits comprise 10 parameters per elemental phase. In order to improve the transferability of the EHT, the AO basis set of a given element simultaneously for different structural phases (e.g., Ti-fcc, -bcc, and -hex) has also been optimized, while the onsite energies have been treated as independent parameters for each phase. For the spin-polarized phases of Fe, Co, and Ni, the coefficient of the d orbitals was additionally varied independently for each spin, since the d bandwidths are larger for the spin minority bands than for the majority ones. The main difference from traditional TB schemes is clear—explicit definition of the AOs. This might look at first glance as a disadvantage, since it requires the calculation of the overlap matrix elements. However, the computational effort involved in constructing the actual overlap $S(\mathbf{k})$ and Hamiltonian $H(\mathbf{k})$ matrices is minimal (only two-center integrals plus the simple EHT formula are involved), and more importantly, for a fixed cutoff radius, it scales linearly with the number of orbitals in the unit cell. The explicit use of AOs can be regarded as advantageous, particularly in what concerns the transferability of the EHT parameters, since the dependence of the overlap terms $S_{\mu M, \nu N}$ on the interatomic distance d_{MN} readily provides a natural scaling law that is not restricted to small variations of d_{MN} . A further advantage is the possibility to obtain the local density of states, while the traditional TB methods only provide real-space-integrated quantities.

The empirically adjusted and consistent set of EHT valence orbital parameters for molecular calculations, based on the Hartree–Fock–Slater (see (4.23)) model of atoms, was recently suggested in [207] for all elements of the periodic table. The parametrization scheme uses individual values of the exchange parameter, α , for each atom. Each value of α was adjusted to reproduce the empirical value of the first ionization energy of the atom considered. The expectation values, energies, and radial functions for all elements of the periodic table have been evaluated on the basis of the Hartree–Fock–Slater model and individual exchange parameters. A consistent set of Slater-type orbital single ζ valence atomic orbital exponents and energies for all elements of the periodic table, suitable for orbital interaction analysis, was presented. These exponents were calculated by fitting the $\langle r \rangle_{\text{STO}}$ moments to numerical empirically adjusted $\langle r \rangle_{\text{HFS}}$ results. In future, these parameters may appear to be useful for TB method calculations of solids after some modifications.

The process in the EHT and TB methods does become iterative if VSIPs are not included in the set of fitted parameters but are adjusted as a function of partial atomic charge as described in the next subsection, since the partial atomic charge depends on the occupied orbitals. Such a scheme is applied for more ionic systems than those studied by the EHT method. The self-consistent one-electron Hamiltonian Mulliken–Rüdenberg calculation scheme is considered in the next subsection.

6.1.2 Iterative Mulliken–Rüdenberg Method for Crystals

The Rüdenberg’s integral approximations for molecules has been described in [199] and in more detail in [208]. This approximation was introduced by Rüdenberg [209] to simplify the calculation of two-electron four-center integrals:

$$(\mu M, \nu N | \sigma P, \lambda L) = \int d\mathbf{r}_1 \int d\mathbf{r}_2 \chi_{\mu M}(\mathbf{r}_1) \chi_{\nu N}(\mathbf{r}_1) \frac{1}{r_{12}} \chi_{\sigma P}(\mathbf{r}_2) \chi_{\lambda L}(\mathbf{r}_2) \quad (6.8)$$

where $\chi_{\mu M}(\mathbf{r})$ is the μ th AO on the M th atom in a molecule. Let $\chi_{1M}, \chi_{2M}, \dots$ be a complete set of orthogonal real orbitals on center M and analogously $\chi_{1N}, \chi_{2N} \dots$, $\chi_{1P}, \chi_{2P} \dots$, and $\chi_{1L}, \chi_{2L} \dots$ —on centers N , P , and L , respectively. If $S_{\mu M, \nu N} = \int d\mathbf{r} \chi_{\mu M}(\mathbf{r}) \chi_{\nu N}(\mathbf{r})$ denotes the overlap integrals between the orbitals $\chi_{\mu M}(\mathbf{r})$ and $\chi_{\nu N}(\mathbf{r})$, then we have the expansions

$$\chi_{\mu M}(\mathbf{r}_1) = \sum_{\omega} S_{\mu M, \omega N} \chi_{\omega N}(\mathbf{r}_1) \quad (6.9)$$

$$\chi_{\nu N}(\mathbf{r}_2) = \sum_{\omega} S_{\omega M, \nu N} \chi_{\omega M}(\mathbf{r}_2) \quad (6.10)$$

whence

$$\begin{aligned} \chi_{\mu M}(\mathbf{r}_1) \chi_{vN}(\mathbf{r}_2) = & \frac{1}{2} \sum_{\omega} [S_{\mu M, \omega N} \chi_{vN}(\mathbf{r}_1) \chi_{\omega N}(\mathbf{r}_2) \\ & + S_{vN, \omega M} \chi_{\mu M}(\mathbf{r}_1) \chi_{\omega M}(\mathbf{r}_2)] \end{aligned} \quad (6.11)$$

Insertion of (6.11) and the analogous formula for the centers L, K in (6.8) expresses the four-center integral in terms of two-center Coulomb integrals and overlap integrals:

$$\begin{aligned} (\mu M, vN | \sigma P, \lambda L) = & \frac{1}{4} \sum_{\omega} \sum_{\omega'} [S_{\mu M, \omega N} S_{\sigma P, \omega' L} (\omega N, vN | \omega' L, \lambda L) \\ & + S_{\mu M, \omega N} S_{\lambda L, \omega' P} (\omega N, vN | \sigma P, \omega' P) \\ & + S_{vN, \omega M} S_{\sigma P, \omega' L} (\mu M, \omega M | \omega' L, vL) \\ & + S_{vN, \omega M} S_{\lambda L, \omega' P} (\mu M, \omega M | \sigma P, \omega' P)] \end{aligned} \quad (6.12)$$

In the Mulliken approximation [210], only the first term in expansion (6.12) is taken so that the one-electron distribution is approximated by

$$\chi_{\mu M}(\mathbf{r}_1) \chi_{vN}(\mathbf{r}_1) \cong \frac{1}{2} S_{\mu M, vN} [\chi_{\mu M}^2(\mathbf{r}_1) + \chi_{vN}^2(\mathbf{r}_1)] \quad (6.13)$$

Using expansions (6.9) and (6.10) for the two-electron distribution and the Mulliken approximation, we obtain

$$\chi_{\mu M}(\mathbf{r}_1) \chi_{vN}(\mathbf{r}_2) \cong \frac{1}{2} S_{\mu M, vN} [\chi_{\mu M}(\mathbf{r}_1) \chi_{\mu M}(\mathbf{r}_2) + \chi_{vN}(\mathbf{r}_1) \chi_{vN}(\mathbf{r}_2)] \quad (6.14)$$

In the Mulliken approximation, the HF operator can be written in the form [211]:

$$\hat{F} = -\frac{\Delta}{2} + \sum_M \hat{V}_M \quad (6.15)$$

where

$$\hat{V}_M = \sum_{\mu}^M P_{\mu} [2(\dots | \chi_{\mu M} \chi_{\mu M}) - (\dots \chi_{\mu M} | \dots \chi_{\mu M})] - \frac{Z_M}{R_M} \quad (6.16)$$

The summation in (6.16) is made over AOs of atom M , P_{μ} is the Mulliken population of the μ th AO, defined as

$$P_\mu = \sum_i^{\text{occ}} C_{i,\mu M}^2 + \sum_{N \neq M} \sum_v^N \sum_i^{\text{occ}} C_{i,\mu M} C_{i,vN} S_{\mu M, vN} \quad (6.17)$$

The action of operator $\hat{V}_M$ on the MO φ is defined by relations:

$$(\dots |\chi_{\mu M} \chi_{\mu M}) \varphi = (\varphi \varphi | \chi_{\mu M} \chi_{\mu M}) \quad (6.18)$$

$$(\dots \chi_{\mu M} | \dots \chi_{\mu M}) \varphi = (\varphi \chi_{\mu M} | \varphi \chi_{\mu M}) \quad (6.19)$$

As in (6.8), the functions depending on coordinates of the first electron are up to the vertical line, those depending on coordinates of the second electron—after the vertical line.

As the valence-electron approximation is supposed to be introduced, the term Z_M/R_M in (6.16) means the electron interaction with the core of atom M in the point-charge approximation. As AO $\chi_{\mu M}(\mathbf{r})$ can be considered as an eigenfunction of operator $(-\frac{\Delta}{2} + \hat{V}_M)$ and introducing the point-charge approximation for Z_M/R_N ($N \neq M$), we obtain the matrix elements of operator (6.15) in the form [212]:

$$F_{\mu M, \mu M} = \varepsilon_{\mu M}(q_M) - \sum_{N \neq M} q_N \left(\chi_{\mu M} \left| \frac{1}{r_N} \right| \chi_{\mu M} \right) \quad (6.20)$$

$$\begin{aligned} F_{\mu M, vN} &= S_{\mu M, vN} (\varepsilon_{\mu M}(q_M) + \varepsilon_{vN}(q_N)) \\ &\quad - \frac{1}{2} S_{\mu M, vN} \sum_{L \neq M, N} q_L \left[\left(\chi_{\mu M} \left| \frac{1}{r_L} \right| \chi_{\mu M} \right) + \left(\chi_{vN} \left| \frac{1}{r_L} \right| \chi_{vN} \right) \right] \\ &\quad - T_{\mu M, vN} \end{aligned} \quad (6.21)$$

In these expressions, $\chi_{\mu M}$ is the μ th atomic orbital on the M th atom; $\varepsilon_{\mu M}(q_M)$ is the ionization potential of the μ th valence orbital on the M th atom with charge q_M ; $S_{\mu M, vN}$ and $T_{\mu M, vN}$ are the overlap and kinetic energy integrals of the μ th and v th orbitals on the M th and N th atom, respectively; $(\chi_{\mu M} | \frac{1}{r_L} | \chi_{\mu M})$ is the core-attraction integral. The effective charge q_M is calculated using the Mulliken population analysis, *that is*, $q_M = \sum_\mu P_\mu$ where the AO population P_μ is defined by (6.17).

The application of the Mulliken–Rüdenberg (MR) approximation to calculate the electronic structure not of the free molecule but of a fragment of an ionic crystal (also called a molecular cluster) requires the summation over an infinite number of lattice sites in terms corresponding to the interaction of the fragment atoms with those of the remaining crystal. For the N th atom in a binary crystal, the field of

ions surrounding the considered fragment can be calculated in the point-charge approximation using the formula:

$$V^N = - \left(\frac{M_c}{a} + \sum_L \frac{\text{sgn}(q_L)}{R_{NL}} \right) |q_R| \quad (6.22)$$

Here, M_c is the Madelung constant, a the nearest-neighbor distance in crystal, q_R the charge ascribed to the lattice ions beyond the fragment under consideration, and L numbers atoms in the fragment considered.

Taking into account (6.22), one can write expressions (6.20) and (6.21) in the form:

$$F_{\mu M, \mu M} = \varepsilon_{\mu M}(q_M) - \sum_{L \neq M} q_L \left(\chi_{\mu M} \left| \frac{1}{r_L} \right| \chi_{\mu M} \right) + V^M \quad (6.23)$$

$$\begin{aligned} F_{\mu M, v N} = & S_{\mu M, v N} (\varepsilon_{\mu M}(q_M) + \varepsilon_{v N}(q_N)) \\ & - \frac{1}{2} S_{\mu M, v N} \left\{ \sum_{L \neq M, N} q_L \left[\left(\chi_{\mu M} \left| \frac{1}{r_L} \right| \chi_{\mu M} \right) + \left(\chi_{v N} \left| \frac{1}{r_L} \right| \chi_{v N} \right) \right] \right. \\ & \left. + V^M + V^N \right\} - T_{\mu M, v N} \end{aligned} \quad (6.24)$$

The MR approximation was extended to the periodic systems in [212, 213].

To describe the band structure of an infinite perfect crystal in the framework of the LCAO method, one should calculate the matrix elements of operator (6.15) using the Bloch sums of atomic orbitals (AO), defined in (4.53):

$$\begin{aligned} \varphi_{\mu \mathbf{k}}(\mathbf{r}) &= L^{-1/2} \sum_j \exp(i \mathbf{k} \mathbf{R}_j) \chi_{\mu}(\mathbf{r} - \mathbf{R}_j) \\ &\equiv L^{-1/2} \sum_j \exp(i \mathbf{k} \mathbf{R}_j) \chi_{\mu j}(\mathbf{r}) \end{aligned} \quad (6.25)$$

Here, $\mathbf{k}$ is the wavevector, μ is the numbers the AOs in the unit cell, $\varphi_{\mu \mathbf{k}}(\mathbf{r})$ is the μ th crystal orbital, $\chi_{\mu j}(\mathbf{r})$ is the μ th AO in the j th unit cell, and L is the number of unit cells in the fundamental region of the crystal.

It is obvious that summation of core-attraction integrals over the whole lattice is very complicated. The values of these integrals decrease as $1/R_{MN}$ with increasing distance, *that is*, special methods are required to estimate their sums. As the values of core-attraction integrals approximate rapidly the value $1/R$ when increasing the interatomic distance, one can hope that the substitution of the Madelung energy for the sums of integrals would turn out to be a quite satisfactory approximation, at least for ionic crystals.

Using the Mulliken approximation in the three-center integrals and the point-charge approximation for V_M , it is shown in [212, 214] that the MR operator matrix elements for a periodic system are given by

$$F_{\mu M, \nu N}(\mathbf{k}) = \frac{1}{2} [2\varepsilon_\mu(q_M, n_M) - ME_M(q_M) + 2\varepsilon_\nu(q_N, n_N) - ME_N(q_N)] \\ \cdot \sum_j \exp(i\mathbf{k} \mathbf{R}_j) S_{\mu M j, \nu N 0} + \frac{1}{2} (q_M + q_N) \sum_j \exp(i\mathbf{k} \mathbf{R}_j) S_{\mu M j, \nu N 0} \frac{1}{R_{M j, N 0}} \\ - \sum_j \exp(i\mathbf{k} \mathbf{R}_j) T_{\mu M j, \nu N 0} - \delta_{MN} \delta_{\mu\nu} \varepsilon_\mu(q_M, n_M) \quad (6.26)$$

Here, the indices $\mu M j$ denote the element of the μ th AO on atom M from primitive unit cell j , defined by translation vector $\mathbf{R}_j$; $\varepsilon_\mu(q_M, n_M)$ is the ionization potential of the orbital on atom M with the atomic charge q_M and orbital population n_M , $S_{\mu M j, \nu N 0}$ and $T_{\mu M j, \nu N 0}$ are overlap and kinetic energy integrals, respectively. The iteration procedure continues until self-consistent effective atomic charges q_M and electronic configuration n_M are obtained. The Madelung energy ME_M at the site of atom M is recalculated at each step of the iterative calculation. It is worth noting that the population analysis scheme developed for molecules should be applied with caution to calculate the effective charges of atoms in crystals. Thus, according to the Mulliken population analysis that is widespread in molecular calculations, the contribution to the total atomic population is computed proportional to the atomic orbital overlap integrals. In the case of crystals, the overlap integrals should be computed with the Bloch sums and, generally speaking, have some meaning other than the molecular ones. To avoid this difficulty, Löwdin's population analysis [215] can be used [214] that is based on a symmetrically orthogonalized basis set and that has therefore no problems connected with the distribution of the overlap population.

In the cyclic-cluster model, the matrix elements (6.26) should be modified [212]. The AOs $\chi_\mu(\mathbf{r})$ have to belong now not only to the atoms in the reference cell but to all the atoms included in the cyclic cluster. Matrix elements (6.26) are calculated only for $\mathbf{k} = 0$, the summation over the crystal is changed by the summation over the cyclic-cluster atoms. For ionic systems, the Madelung field of the surrounding crystal can be taken into account by subtracting from the Madelung energy at the site of an atom the part due to the interaction with atoms directly included in the cyclic cluster. To satisfy the PBC introduction for the cyclic cluster, the overlap integrals have to satisfy the condition $(\chi_{\mu M}(\mathbf{r} - \mathbf{R}_j + \mathbf{A}) \chi_{\nu N}(\mathbf{r})) = S_{\mu M j, \nu N}$ where $\mathbf{A}$ is the translation vector of the cyclic cluster as a whole (see Chap. 3).

The MR approximation was applied for electronic-structure calculations of both perfect crystals (alkali halides [212], MgO and CaO [216], PbO [217], corundum [218]), point defects in solids [219–224], and surfaces [214].

The general analysis of Rüdberg's approximation in the HF LCAO method for molecules [208] and solids [213] has shown that EHT and zero differential overlap (ZDO) approximations can be considered as particular cases of Rüdberg's integral

approximation. ZDO methods, considered in the next section, were applied to a wide class of molecules and solids from purely covalent to purely ionic systems. Therefore, they are more flexible compared to the MR approximation, which is more appropriate for ionic systems.

6.2 Zero Differential Overlap Approximations for Molecules and Crystals

6.2.1 Zero Differential Overlap Approximations for Molecules

As was seen in Sect. 6.1 in EHT, the AO basis functions are only used for the calculation of overlap integrals (molecules) or lattice sums of overlap integrals (crystals). In the MR method, kinetic energy integrals or their lattice sums are also included. These integrals in fact can be expressed through overlap integrals. All other contributions to the one-electron Hamiltonian matrix elements are based on empirical parameters.

As we have seen, EHT is a nonself-consistent method, but the self-consistency over charge and configuration is included in the MR approximation. The *ab initio* HF SCF method requires the self-consistent calculation of the density matrix (see Chap. 4). This feature of the HF approach is maintained in the semiempirical methods, based on the zero differential overlap (ZDO) approximation. This approximation is used to reduce the number of multicenter integrals appearing in HF LCAO calculations.

In the ZDO approximation, the differential overlap $\chi_\mu(\mathbf{r}_1)\chi_\nu(\mathbf{r}_2)d\mathbf{r}_1d\mathbf{r}_2$ of valence AO basis functions is supposed to be zero for any $\mu \neq \nu$ both for $\mathbf{r}_1 = \mathbf{r}_2$ and $\mathbf{r}_1 \neq \mathbf{r}_2$. The ZDO approximation means that the AO basis is assumed to be orthogonal ($S_{\mu\nu} = \int \chi_\mu(\mathbf{r})\chi_\nu(\mathbf{r})d\mathbf{r} = \delta_{\mu\nu}$). A recent review by Bredow and Jug [225] gives a brief summary of the basis features of ZDO semiempirical methods together with examples of their use. These authors are convinced that “the development of semiempirical methods and their extension to a growing number of research areas has been a continuous process over the last 4 decades and there is apparently no end to be seen.” This is demonstrated by the large number of semiempirical studies in organic, inorganic, and physical chemistry, biochemistry, drug design, crystallography, and surface science.

Depending on the level of the approximations used for other integrals, ZDO methods differ. In the CNDO (complete neglect of differential overlap) method [195, 226], all two-electron integrals are approximated by Coulomb integrals according to

$$(\mu\nu|\lambda\sigma) = \int \chi_\mu(\mathbf{r}_1)\chi_\nu(\mathbf{r}_1)\frac{1}{r_{12}}\chi_\lambda(\mathbf{r}_2)\chi_\sigma(\mathbf{r}_2)d\mathbf{r}_1d\mathbf{r}_2 = \delta_{\mu\nu}\delta_{\lambda\sigma}(\mu\mu|\lambda\lambda) \quad (6.27)$$

and only two-center electron-repulsion integrals $(\mu\mu|\lambda\lambda) = \gamma_{MN}$ are retained (M and N are the atoms on which basis functions $\chi_\mu(\mathbf{r})$ and $\chi_\nu(\mathbf{r})$ reside, respectively). The independence of this integral on the angular part of AOs restores the AOs hybridization invariance of the original HF operator matrix elements, *that is*, it is supposed that $(S_M S_M | S_N S_N) = (P_M P_M | P_N P_N) = (P_M S_M | P_N S_N) = \gamma_{MN}$. The two-center Coulomb integral γ_{MN} can either be computed explicitly from s -type STOs (6.1) or it can be treated as a parameter. The one-center Coulomb integral γ_M is parameterized using a so-called Pariser–Parr [227] approximation $\gamma_M = I_M - A_M$, where I_M and A_M are the atomic ionization potential and electron affinity, respectively. The parameter γ_M can be expressed with a commonly tabulated semiempirical parameter $U_{\mu\mu}$ (the energy of interaction of electron-occupying AO $\chi_\mu(\mathbf{r})$ with the core of atom M):

$$U_{\mu\mu} = -I_\mu - (Z_\mu - 1)\gamma_M \quad (6.28)$$

$$U_{\mu\mu} = -0.5(I_\mu + A_\mu) - (Z_A - 1/2)\gamma_M \quad (6.29)$$

Equations (6.28) and (6.29) are used in CNDO/1 and CNDO/2 methods, respectively. For the two-center integral γ_{MN} , the Mataga–Nishimoto [228]

$$\gamma_{MN}(\text{eV}) = \frac{14.3986}{R_{AB} + \delta}, \quad \delta(\text{eV}) = \frac{14.3986}{(\gamma_{AA} + \gamma_{BB})^{1/2}} \quad (6.30)$$

or Ohno [229]

$$\gamma_{AB}(\text{eV}) = \frac{14.3986}{\sqrt{R_{AB} + \delta}} \quad (6.31)$$

formulas are adopted, where $R_{AB}(\text{\AA})$ is the interatomic distance. At large distance, γ_{AB} in both cases goes to $1/R_{AB}$, as expected for widely separated charge clouds, while at short distances, it approaches the average of the two one-center parameters.

The one-electron terms for offdiagonal matrix elements are defined as

$$h_{\mu\nu} = \beta_{\mu\nu} = 0.5(\beta_M + \beta_N)S_{\mu\nu} \quad (6.32)$$

where $S_{\mu\nu}$ is the overlap matrix element computed using Slater-type basis functions $\chi_\mu(\mathbf{r})$ and $\chi_\nu(\mathbf{r})$, centered on atoms M and N , respectively; the β_M, β_N values are semiempirical parameters. Note that computation of the overlap is carried out for every combination of basis functions, even though in the secular equation $\text{FC} = \text{CE}$ itself S is defined in ZDO approximation as $S_{\mu\nu} = \delta_{\mu\nu}$. There are, in effect, two different S matrices, one for each purpose. The β parameters are entirely analogous to the parameters β in EHT—they provide a measure of the strength of through-space interactions between atoms [230]. As β parameters are intended for completely general use, it is not necessarily obvious how to assign them a numerical value, unlike the situation that obtains in EHT. Instead, β values for CNDO were originally adjusted to reproduce certain experimental quantities.

The diagonal $F_{\mu\mu}$ and nondiagonal $F_{\mu\nu}$ matrix elements in the CNDO approximation for molecules are defined by

$$F_{\mu\mu} = U_{\mu\mu} + (P_M - 1/2P_{\mu\mu})\gamma_M + \sum_{N \neq M} (P_N - Z_N)\gamma_{MN} \quad (6.33)$$

$$F_{\mu\mu'} = -0.5P_{\mu\mu'}\gamma_M \quad (6.34)$$

$$F_{\mu\nu} = \beta_{MN}S_{\mu\nu} - 0.5P_{\mu\nu}\gamma_{MN} \quad (6.35)$$

AOs χ_μ and $\chi_{\mu'}$ in (6.34) are supposed to belong to the same atom M . In (6.34), Z_M is the atomic core charge, $P_{\mu\nu}$ are the density matrix elements in the LCAO approximation (see (4.37)), $P_M = \sum_\mu^A P_{\mu\mu}$ is the electron population of atom M , and the resonance integral $\beta_{\mu\nu}$ is taken as β_{MN} , *that is*, depends only on the atom type, but not on a particular orbital of this atom. The CNDO method represents a vast simplification of HF theory, reducing the number of two-electron integrals having nonzero values from formally N^4 to N^2 . Furthermore, these integrals are computed by trivial algebraic formulae, not by explicit integration, and between any pair of atoms all of the integrals have the same value irrespective of the atomic orbitals involved. Similarly, evaluation of one-electron integrals is also entirely avoided (excluding overlap integrals), with numerical values for those portions of the relevant matrix elements coming from easily evaluated formulae. Historically, a number of minor modifications to the conventions outlined above were explored, and the different methods had names like CNDO/1, CNDO/2, and CNDO/BW, [195].

The computational simplifications inherent in the CNDO method are not without chemical cost, as might be expected. Like EHT, CNDO is quite incapable of accurately predicting good molecular structures. Furthermore, the electronic interactions on a single atom are not correctly reproduced due to the ZDO approximation for the different AOs of the same atom. In an attempt to overcome this deficiency of the CNDO scheme, the intermediate neglect of differential overlap (INDO) approximation was introduced [231] to permit a more flexible handling of electron–electron interactions on the same center. In this case, the different values of one-center two-electron integrals are used for different AOs: $(ss|ss) = G_{ss}$, $(ss|pp) = G_{sp}$, $(pp|pp) = G_{pp}$, $(sp|sp) = L_{sp}$. These integrals are in practice estimated from spectroscopic data. In the INDO scheme, the valence bond angles are predicted with much greater accuracy than is the case for CNDO. Nevertheless, overall molecular geometries predicted from INDO tend to be rather poor. Preliminary efforts to address this problem have been reported only recently [232]. A careful parametrization of INDO for spectroscopic problems [233] was described in an INDO/S calculation scheme whose parametrization was later extended to most of the elements in the periodic table [234]. In a purely terminological sense, one can make a distinction between the INDO semiempirical method and the INDO/S model [97]. The latter is a particular parametrization of the INDO method designed for spectroscopic applications. The MINDO/3 model [235], the third version of the

modified INDO method, included some modifications: different orbital exponents were used for s - and p -orbitals on the same atom, resonance integrals β_{MN} between two atoms were split into pairs corresponding to $s-s$, $s-p$, $p-p$ orbital interactions, and some empirical modifications to the nuclear repulsion energy were introduced. The MINDO/3 model allowed prediction of heats of formation with the mean absolute error of 11 kcal/mole, 0.7 eV for ionization potentials, and 0.022 Å for bond lengths.

In both CNDO and INDO methods, the two-center two-electron integral takes the value $(\mu\mu|\nu\nu) = \beta_{MN}$, irrespective of which orbitals on atoms M and N are considered.

The neglect of diatomic differential overlap (NDDO) method [226] is an improvement over the INDO approximation, since the ZDO approximation is applied only for orbital pairs centered at different atoms. Thus, all integrals $(\mu\nu|\lambda\sigma)$ are retained provided μ and ν are on the same atomic center and λ and σ are on the same atomic center, but not necessarily the center hosting μ and ν . In principle, the NDDO approximation should describe long-range electrostatic interactions more accurately than INDO. Most modern semiempirical models (MNDO, AM1, PM3) are NDDO models.

The modified neglect of the diatomic overlap (MNDO) method [236] led to improved agreement with experiment. In the two-electron integral calculation, the continuous charge clouds were replaced with classical multipoles. Thus, an ss product was replaced with a point charge, an sp product was replaced with a classical dipole (represented by two point charges slightly displaced from the nucleus along the p orbital axis), and a pp product was replaced with a classical quadrupole (again represented by point charges). The magnitudes of the moments, being one-center in nature, are related to the parameterized integrals appearing in the INDO method. By adopting such a form for the integrals, their evaluation is made quite simple, and so too is evaluation of their analytic derivatives with respect to nuclear motion. To complete the energy evaluation by the MNDO method, the nuclear repulsion energy is added to the SCF energy. The parameters of the MNDO model were optimized against a large test set of molecular properties (within the assumption of a valence orbital set comprised only of s and p orbitals).

In addition, a modified MNDO model explicitly adding electron correlation effects (MNDOC) by second-order perturbation theory was described by Thiel [237]. By explicitly accounting for electron correlation in the theory, the parameters do not have to absorb the effects of its absence from HF theory in some sort of average way.

Later, two modifications of MNDO were introduced [97, 225]. The most prominent of these are the Austin model 1 (AM1) by Dewar et al. [236] and the parametric method 3 (PM3) by Stewart [238]. In principle MNDO, AM1 and PM3 methods differ only in the parametrization and in the empirical function f_{MN} in the core–core repulsion:

$$V_{nn} = \sum_{M>N} Z_M^* Z_N^* \gamma_{MN} + f_{MN} \quad (6.36)$$

where

$$f_{MN} = Z_M^* Z_N^* \gamma_{MN} (\exp(-\alpha_M R_{MN}) + \exp(-\alpha_N R_{MN}))$$

and Z^* is the effective core charge.

A variety of modifications of the original methods is now available. AM1 and PM3 have been extended for the treatment of transition-metal compounds by inclusion of d orbitals in the valence basis; the Green's function technique has been implemented in MNDO-type methods for the calculation of ionization potentials and electron affinities; a parameterized variational technique is used for the calculation of molecular polarizabilities and hyperpolarizabilities within the MNDO, AM1, and PM3 methods [225].

The most important modifications of the MNDO method are the use of effective core potentials for the inner orbitals and the inclusion of orthogonalization corrections in a way as was suggested and implemented a long time ago in the SINDO1 method [239] at first developed for organic compounds of first-row elements and later extended to the elements of the second and third row [240, 241].

The most important feature of the SINDO1 method is that an orthogonalization transformation of the basis functions is taken into account explicitly in solving the HF LCAO equations. The one-electron integral matrix H is transformed to Löwdin symmetrically orthogonalized [215] AOs $\chi^\lambda = S^{-1/2} \chi$:

$$H^\lambda = S^{-1/2} H S^{-1/2} \quad (6.37)$$

Matrix $S^{-1/2}$ can be expanded in a series

$$\begin{aligned} S &= I + \sigma \\ S^{-1/2} &= I - 1/2\sigma + 3/8\sigma^2 - \dots \end{aligned} \quad (6.38)$$

where I is the unit matrix and σ the remaining two-center overlap matrix. The expansion is truncated in such a way that only terms up to second order in the overlap are retained.

Another special feature of SINDO1 is the treatment of inner orbitals by a local pseudopotential introduced in [242]. Two-center one-electron integrals $H_{\mu\nu}^\lambda$ are calculated by the following empirical formula:

$$H_{\mu\nu}^\lambda = L_{\mu\nu} + \Delta H_{\mu\nu}, \quad \mu \in M, \quad \nu \in N \quad (6.39)$$

Here, L is a correction to the Mulliken approximation for the kinetic energy, and ΔH is entirely empirical and contains adjustable bond parameters. These are optimized in order to minimize the deviation from experiment for a set of reference compounds. Two sets of Slater-orbital exponents are used: one (ζ^U) for intra-atomic integrals and the other (ζ) for interatomic integrals. Experimental heats of formation are calculated from binding energies E_B , which are corrected by the zero-point energies obtained from vibration analyses. This is theoretically more sound than

in MNDO, AM1, and PM3, where binding energies are parameterized directly to reproduce experimental heats of formation without reference to zero-point energies.

Recently, a new version MSINDO was developed by substantial modifications in the SINDO1 formalism. The parameters are now available for the elements H, C–F, Na–Cl, Sc–Zn, and Ga–Br [243–246] for Li–B and K–Ca[247].

In MSINDO the standard basis set for elements Al–Cl has been changed from $\{3s, 3p\}$ to $\{3s, 3p, 3d\}$ in order to account for hypervalent compounds [243]. For compounds containing Na and Mg, an inclusion of $3d$ functions was considered inconsistent, because these atoms already contain $3p$ functions for polarization. Moreover, test calculations showed that the $3d$ functions on these atoms had only insignificant effects on the molecular properties. As for SINDO1, the H basis set can be augmented with a $2p$ shell for the treatment of hydrogen bonds. All Slater–Condon atomic parameters are calculated analytically for the one-center two-electron integrals and one-electron integrals $U_{\mu\mu}$. For the higher multipole terms, this differs from SINDO1, where these terms were taken from experimental spectra. The MSINDO procedure is more consistent since all parameters are derived at the same level of theory. To maintain rotational invariance, a number of one-center hybrid integrals have to be included in the case of d functions [248]. This was already implemented in SINDO1 and was kept in MSINDO. The core integrals U_{3d} of second- and third-row elements were scaled by a screening potential K_{sc} in order to avoid unrealistically high populations for the $3d$ shell:

$$U'_{3d} = (1 - K_{sc})U_{3d} \quad (6.40)$$

For second-row elements, a fixed value of $K_{sc} = 0.15$ is used. For third-row elements, U_{3d} , U_{4s} , and U_{4p} were scaled with different screening potentials [246].

The most important change in MSINDO with respect to SINDO1 is a modification of the approximate Löwdin orthogonalization of the basis [243]. Only the first-order terms in overlap are retained in (6.38). In SINDO1, the expansion was to second order. If only first-order terms are taken into account, no transformation of the two-electron integrals is necessary. The one-electron integrals are transformed:

$$\tilde{H}_{\mu\mu'}^{\lambda} = H_{\mu\mu'}^{\lambda} - f^M \frac{1}{2} \sum_{N \neq M} \sum_v^N (L_{\mu v} S_{v\mu'} + S_{\mu v} L_{v\mu'}) \quad (6.41)$$

The correction factor, f^M , accounts for the neglect of higher-order terms in the truncated expansion (6.38). Its value depends on the number of basis functions on atom M . f^M is 1 for an $\{s\}$ basis, 0.75 for an $\{s, p\}$ basis, and 0.5 for an $\{s, p, d\}$ basis.

We considered SINDO1–MSINDO methods in more detail as these methods were successfully applied in calculations of bulk solids and surfaces in the embedded and cyclic-cluster models (see Sect. 6.3). The role of long-range interactions in solids increases, compared to the case of molecules. In order to better describe long-range interactions, in particular at surfaces, dipole–monopole and dipole–dipole

terms were added to the MSINDO formalism following an early suggestion by Voigt [249]. After modification of the formalism, a complete reparametrization of all elements had to be performed. The new version, called MSINDO+, was tested for some cases where SINDO1 and MSINDO gave results in disagreement with experiment.

It should be noted that an analysis of some systematic errors of the ZDO approximation [250] allowed an improved semiempirical approach to be developed [251]. In this approach, the R udenberg approximation is used for diatomic overlap densities appearing in Coulomb integrals; the Fock matrix is simplified such that its construction scales with N^2 instead of N^4 in *ab initio* methods, if N is the dimension of the basis set. Thus, the one-electron and two-electron Coulomb parts of the Fock matrix are formulated explicitly in an atomic orbital (AO) basis, whereas the ZDO approximation is restricted to the two-electron exchange part. The complete two-electron Coulomb part of the Fock matrix is explicitly subjected to the L owdin transformation. The proposed formalism is not necessarily an empirical one because, in principle, all matrix elements can be calculated exactly. Since only two-center integrals appear, one can use a Slater instead of the Gaussian basis of *ab initio* methods. However, if the formalism is restricted to the valence electrons as in normal semiempirical methods, some parametrization is unavoidable. In this case, an additional pseudopotential accounting for the effects of core-valence orthogonality should be implemented. It may also be useful to absorb possible errors arising from the R udenberg approximation into the parametrization of the two-electron integrals.

Hybrid approaches combining *ab initio* or DFT and semiempirical approaches have become popular. As an example, we can refer to LEDO (limited expansion of differential overlap) densities application to the density-functional theory of molecules [252]. This LEDO–DFT method should be well suited to the electronic-structure calculations of large molecules, and in the authors' opinion, its extension to Bloch states for periodic structures is straightforward. In the next sections, we discuss the extension of CNDO and INDO methods to periodic structures—models of an infinite crystal and a cyclic cluster.

6.2.2 Complete and Intermediate Neglect of Differential Overlap for Crystals

The first applications of ZDO methods for extended systems refer to the electronic-structure calculations of regular polymer chains when the one-dimensional (1D) periodicity is taken into account. The corresponding modifications of molecular ZDO equations can be found in the literature: for the CNDO method in [253–256], for the INDO and MINDO methods in [257, 258], and for the MNDO, PM3, and AM1 methods in [259–262].

The CNDO method extended to the two-dimensional (2D) periodicity case was applied in regular chemisorption studies of hydrogen and oxygen on a graphite surface [197, 263–265]. The equations of the CNDO method for three-dimensional (3D) solids were given in [197, 263, 265–271]; the periodic MINDO method is considered in [272–274].

The main features of the CNDO and INDO approaches to periodic systems are similar to those used for molecules. A valence-electron approximation is adopted, which implies that only the valence electrons are in the bonding region and are polarized by the presence of neighboring atoms [267]. For periodic systems, the LCAO approximation is based on use of the Bloch sums (4.53) of AOs $\chi_{\mu n}(\mathbf{r}) = \chi_{\mu}(\mathbf{r} - \mathbf{R}_n)$ numbered by index μ (labels all AOs in the reference primitive unit cell) and by the direct lattice translation vector $\mathbf{R}_n$ ($n = 0$ for the reference cell).

In the ZDO approximation, AOs are supposed to be orthogonal both in the intracell and intercell overlap integrals:

$$S_{\mu 0, \nu n} = \int \chi_{\mu 0}(\mathbf{r}) \chi_{\nu n}(\mathbf{r}) d\mathbf{r} = \delta_{0n} \delta_{\mu\nu} \quad (6.42)$$

The two-electron integrals are approximated by Coulomb integrals γ_{MN}^{0n} , calculated with s functions of the M th atom from reference cell and the N th atom from the cell n :

$$(\mu 0, \nu n | \lambda i, \sigma i') = \delta_{0n} \delta_{\mu\nu} \delta_{ii'} \delta_{\lambda\sigma} \gamma_{MN}^{0i} \quad (6.43)$$

The one-electron matrix elements $H_{\mu 0, \nu n}$ are approximated by $\beta_{MN} S_{0\mu, \nu n}$, where the resonance integrals β_{MN} depend only on the type of atoms M and N to which the AOs μ and ν refer. In particular, in the CNDO/2 version of the CNDO method for the crystal, the diagonal one-electron matrix elements are taken in the form:

$$H_{\mu 0, \mu 0} = U_{\mu\mu} + Z_M \gamma_{MN}^{00} - \sum_{n, N} Z_N \gamma_{MN}^{0n} \quad (6.44)$$

The difference of (6.44) from its molecular analog is defined by the lattice summation over all atoms N (including $M = N$) in the reference cell and in different unit cells of a crystal. In the model of an infinite crystal, these lattice sums are infinite. All the simplifications mentioned are introduced in the Fock and overlap matrices (4.56) and HF LCAO equations (4.57) for periodic systems so that one obtains instead of (4.56) and (4.57):

$$S_{\mu\nu}^{\text{ZDO}}(\mathbf{k}) = \sum_n \delta_{0n} \delta_{\mu\nu} \exp(i\mathbf{k} \mathbf{R}_n) = \exp(i\mathbf{k} \mathbf{R}_0) \quad (6.45)$$

$$\sum_v \left\{ F_{\mu\nu}^{\text{ZDO}}(\mathbf{k}) \exp(i\mathbf{k}(\mathbf{R}_n - \mathbf{R}_0)) - E_i(\mathbf{k}) C_{i\mu}(\mathbf{k}) \right\} = 0 \quad (6.46)$$

Let $\mathbf{R}_0$, the lattice vector of the reference cell, correspond to the origin of the coordinate system. Then the core (H) and Fock (F) matrix elements have the following form within the CNDO formalism:

$$H_{\mu\mu}(\mathbf{k}) = U_{\mu\mu} + Z_M \gamma_{MM}^{00} - \sum_N \sum_{n=0}^{L-1} Z_N \gamma_{MN}^{0n} + \sum_{n=1}^{L-1} \beta_M^0 S_{\mu\mu}^{0n} \exp(i\mathbf{k}\mathbf{R}_n)$$

$$H_{\mu\nu} = \sum_{n=0}^{L-1} \beta_{MN}^{00} S_{\mu\nu}^{0n} \exp(i\mathbf{k}\mathbf{R}_n) \quad (6.47)$$

$$F_{\mu\mu}(\mathbf{k}) = H_{\mu\mu}(\mathbf{k}) + \frac{1}{L} \sum_{N,v} \sum_{n=0}^{L-1} \sum_{\mathbf{k}'} P_{\nu\nu}(\mathbf{k}') \gamma_{MN}^{0n}$$

$$- \frac{1}{2L} \sum_{n=0}^{L-1} \sum_{\mathbf{k}'} P_{\mu\mu}(\mathbf{k}') \gamma_{MN}^{0n} \exp(i(\mathbf{k} - \mathbf{k}')\mathbf{R}_n)$$

$$F_{\mu\nu}(\mathbf{k}) = H_{\mu\nu}(\mathbf{k}) - \frac{1}{2L} \sum_{n=0}^{L-1} \sum_{\mathbf{k}'} P_{\mu\nu}(\mathbf{k}') \gamma_{MN}^{0n} \exp(i(\mathbf{k} - \mathbf{k}')\mathbf{R}_n) \quad (6.48)$$

As in the HF LCAO method, the calculation of the wavevector of the $\mathbf{k}$ -dependent density matrix

$$P_{\mu\nu}(\mathbf{k}) = 2 \sum_i^{\text{occ}} C_{i\mu}^*(\mathbf{k}) C_{i\nu}(\mathbf{k}) \quad (6.49)$$

requires the summation over occupied crystalline orbitals (i) that are themselves defined as a linear combination of the basis atomic orbitals. The HF method allows both an all-electron calculation and a valence-electron approximation when the atomic core pseudopotentials are introduced. In both cases, the AOs are represented by GTO. In the CNDO method for crystals, only the valence atomic orbitals are included and represented by a minimal Slater basis set. We return to the basis-set consideration in Chap. 8.

Equations (6.47) and (6.48) contain an explicit $\mathbf{k}$ dependence via the phase factors $\exp(i\mathbf{k}\mathbf{R}_n)$ and an implicit $\mathbf{k}$ -dependence via summations over $\mathbf{k}'$. Invoking the special $\mathbf{k}$ -points theory (see Sect. 4.2.2), one need only use a small set of $\mathbf{k}'$ -points to approximate the integral over BZ.

In (6.48) and (6.49), $S_{\mu\nu}^{0n}$ and γ_{MN}^{0n} are the overlap and Coulomb integrals for atomic orbital μ on atom M in the primitive unit cell 0 and atomic orbital ν on atom N in the cell $\mathbf{R}_n$. $U_{\mu\mu}$ describes the interaction of an electron with the atomic core of the atom M with the core charge Z_M (this is equal to the number of valence electrons of atom M). The Coulomb integrals γ_{MN} and the bonding parameters β_{MN} are assumed to be orbitally independent.

It follows from (6.49) that in the CNDO approximation, the nonlocal exchange is taken into account as nondiagonal elements of the Fock matrix contain nondiagonal elements $P_{\mu\nu}(\mathbf{k}')$ of the density matrix. This means that lattice sums in this case

are divergent, see Sect. 4.3.3. Indeed, for sufficiently large $\mathbf{R}_n$, the two-electron integrals γ_{MN}^{0m} in the exchange part of (6.48) may be approximated by $1/|\mathbf{r}_M + \mathbf{r}_N - \mathbf{R}_n|$ where $\mathbf{r}_M, \mathbf{r}_N$ are the vectors defining the positions of atoms M and N in the reference cell. Therefore, the convergence of the lattice sum over n is defined by the convergence of the lattice sum:

$$S_j(\mathbf{k}) = \sum_n \frac{\exp(i(\mathbf{k} - \mathbf{k}_j)\mathbf{R}_n)}{|\mathbf{R}_n + \mathbf{r}_m - \mathbf{r}_N|} \quad (6.50)$$

The sum (6.50) can be calculated for $\mathbf{k} \neq \mathbf{k}_j$, for example, by the Ewald method. However, for $\mathbf{k} = \mathbf{k}_j$, the series (6.50) appears to be divergent [90]. This divergence is the result of the general asymptotic properties of the approximate density matrix calculated by the summation over the special points of BZ (see Sect. 4.3.3). The difficulties connected with the divergence of lattice sums in the exchange part have been resolved in CNDO calculations of solids by introduction of an interaction radius for exchange [266,267] or of distance-dependent modulating functions that weight certain Coulomb interaction terms [270]. Detailed studies of the HF LCAO density matrix properties (see Sect. 4.3.3) allow an interpolation procedure to be suggested for constructing an approximate density matrix for periodic systems, which ensures a balance between the direct lattice and BZ summations. Furthermore, this analysis is important for the cyclic-cluster ZDO calculations as it allows an additional parameter (exchange radius) introduction to be omitted (see Sect. 6.3).

The extension of INDO and MINDO semiempirical methods to periodic systems has no principal differences compared with the CNDO method. The advantage of these methods is the possibility to make spin-dependent calculations as is done in the UHF method.

The considered CNDO method for periodic systems formally corresponds to the model of an infinite crystal or its main region consisting of L primitive cells. This semiempirical scheme was also applied for the cyclic-cluster model of a crystal allowing the BZ summation to be removed from the two-electron part of matrix elements. In the next section, we consider ZDO methods for the model of a cyclic cluster.

6.3 Zero Differential Overlap Approximation in Cyclic-Cluster Model

6.3.1 Symmetry of Cyclic-Cluster Model of Perfect Crystal

In Sect. 4.2.1, we introduced supercell transformation (4.77) in the direct lattice allowing generation of special points of the BZ in the calculation of the one-electron density matrix of the perfect crystal. In this consideration, the perfect crystal was supposed to be infinite or represented by its main region. The latter was defined as a block on which opposite-side periodic boundary conditions are imposed. The main

region of a crystal can be called a cyclic cluster of huge size (in the shape of a parallelepiped with large edges), modeling the infinite crystal and maintaining its translation symmetry.

The idea to use relatively small cyclic clusters for comparative perfect-crystal and point-defect calculations appeared as an alternative to the molecular-cluster model in an attempt to handle explicitly the immediate environment of the chemisorbed atom on a crystalline surface [275] and the point defects in layered solids [276, 277] or in a bulk crystal [278, 279, 282, 283]. The cluster is formed by a manageable group of atoms around the defect, and the difference between the molecular-cluster model (MCM) and the cyclic-cluster model (CCM) is due to the choice of boundary conditions for the one-electron wavefunctions (MOs). Different notations of CCM appeared in the literature: molecular unit cell approach [278], small periodic cluster [276], and large unit cell [279, 280]. We use here the cyclic-cluster notation.

In MCM (as in molecules), MOs are supposed to be orthonormalized in the whole space; this condition is also fulfilled for the molecular clusters embedded by some or another means into the crystalline environment. Recent applications of the molecular-cluster model and MO calculations for materials design in the Hartree–Fock–Slater method are discussed in [281].

In the CCM model the periodic boundary conditions are introduced for MOs of a cluster having the shape of a supercell of a perfect crystal so that MOs are orthonormal in the field of the cyclic cluster chosen. Postponing to Chap. 10, the more detailed discussion of molecular models of defective crystals, we would like to note here the difference between the supercell model (SCM) and CCM for point defects. In the former, PBC are introduced for the main region of a crystal so that the point defect is periodically repeated over the crystalline lattice, in the latter the single point defect is considered. This means that CCM is conceptually a supercell-type approach but is technically more closely related to the simple MCM [284].

We discuss here the symmetry of CCM for perfect crystal [13, 285–289]. The symmetry of defective crystal in CCM is considered in Chap. 10.

To define a finite cyclic system, let us make a linear transformation of the primitive lattice translation vectors

$$: \mathbf{A}_j = \sum_i l_{ji} \mathbf{a}_j, \quad L = |\det l| \geq 1 \quad (6.51)$$

where the integer coefficients l_{ji} form the matrix l . The transformation (6.51) for $L > 1$ determines a supercell (large unit cell) of the direct lattice. It may be chosen in the form of a parallelepiped with vectors $\mathbf{A}_j$ as edges or in the form of the corresponding Wigner–Seitz unit cell.

The particular form of the matrix l in (6.51) defines the supercell shape and its volume (which is L times larger than that of a primitive unit cell) and the symmetry of the direct lattice based on the group T_A of the translations:

$$\mathbf{A}_n = \sum_{j=1}^3 n_j \mathbf{A}_j, \quad n_j \text{ are arbitrary integers} \quad (6.52)$$

The group T_A is an invariant subgroup of T_a (translation group of the infinite lattice with primitive translation vectors $\mathbf{a}_i$) so that the cosets $(E|\mathbf{a}^{(i)})T_A$ ($i = 1, 2, \dots, L$) in the decomposition

$$T_a = \sum_{i=1}^L (E|\mathbf{a}^{(i)})T_A \quad (6.53)$$

form the factor group $T_a/T_A = T^{(A)}$ of order L . The so-called inner translations of the supercell are assumed to be chosen as $\mathbf{a}^{(i)}$ in (6.53).

Figure 6.1a shows the supercell of the plane hexagonal lattice of boron nitride, BN, formed by the diagonal $l = \begin{pmatrix} 3 & 0 \\ 0 & 3 \end{pmatrix}$ matrix, with $L = 9$.

A cyclic cluster $C^{(A)}$ is defined as a supercell with identical opposite faces, *that is*, the periodic boundary conditions are introduced for the chosen supercell itself (not for the main region of a crystal!). In particular, in the supercell, shown on Fig. 6.1a, the atoms with the primed numbers are supposed to be identical with the atoms of the supercell, having the same unprimed numbers. This means that the translation of a supercell as a whole is equivalent to the zero translation.

The translation symmetry of $C^{(A)}$ is characterized by a three-dimensional cyclic group $\widetilde{T}^{(A)}$ of order L with the elements $(E|\mathbf{a}^{(i)})$ from (6.53) and multiplication law modulo T_A . In our example, this group consists of 9 inner translations of the B_9N_9 supercell, *that is*, translations of the BN primitive unit cell, consisting of one formula unit. The group $\widetilde{T}^{(A)}$ is isomorphic to the factor group $T^{(A)}$.

Let $l^{(a)}(R)$ be the transformation matrix of the translation vectors $\mathbf{a}_i$ under the point-symmetry operation $R \in F$:

$$R\mathbf{a}_i = \sum_{i'} l_{i'i}^{(a)}(R)\mathbf{a}_{i'} \quad (6.54)$$

The corresponding transformation matrix for the translation vectors $\mathbf{A}_j$ in (6.51) is

$$R\mathbf{A}_j = \sum_{j'} l_{j'j}^{(A)}(R)\mathbf{A}_{j'}, \quad l^{(A)}(R) = l^{-1}l^{(a)}(R)l \quad (6.55)$$

The operation $(R'|\mathbf{v}' + \mathbf{a}_n) \in G$ is compatible with the translation symmetry of the lattice composed of supercells, if the vectors $R'\mathbf{A}_j$ are integer linear combinations of the vectors $\mathbf{A}_j$, *that is*, the matrix $l^{(A)}(R')$ is integer. All these operations $(R'|\mathbf{v}' + \mathbf{a}_n)$ form a group $G' \subset G$. The rotations R' form a point group $F' \subset F$ of order $n_{F'} \leq n_F$. As

$$(R'|\mathbf{v}' + \mathbf{a}_n)(E|\mathbf{A}_j)(R'|\mathbf{v}' + \mathbf{a}_n)^{-1} = (E|R'\mathbf{A}_j) \quad (6.56)$$

the translation group T_A is an invariant subgroup of the group G' . The cosets in the decomposition

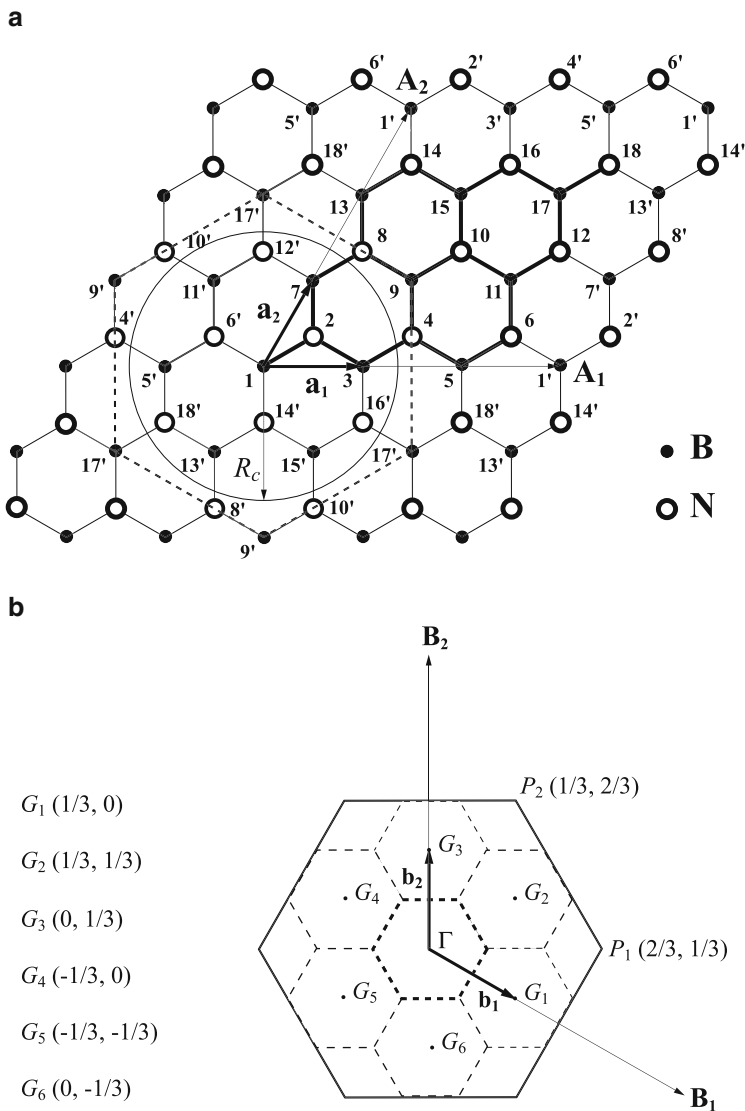


Fig. 6.1 Supercell (a) and small Brillouin zone (b) for hexagonal plane lattice of boron nitride BN. Atoms 1–18 belong to the supercell, the atoms with the primed numbers are supposed to be identical with the corresponding atoms, belonging to the supercell

$$G' = \sum_{i=1}^L \sum_{s=1}^{n_{F'}} (R'_s | v'_s + a^{(i)}) T_A \quad (6.57)$$

form the factor group $G^{(A)} = G' / T_A$ of the order $n_{F'} L$.

The coset representatives $(R'_s|\mathbf{v}'_s + \mathbf{a}^{(i)})$ in (6.57) contain the inner translations $\mathbf{a}^{(i)}$ of the supercell ($i = 1, 2, \dots, L$) and rotational parts $R' \in F'$, forming the point group of the space group G' .

Let us introduce a modified multiplication law modulo T_A , which does not distinguish between the translations of the group T_A . The set of $n_{F'}/L$ elements $(R'_s|\mathbf{v}'_s + \mathbf{a}^{(i)})$ forms a group $\widetilde{G}^{(A)}$ (modulo T_A), which is the symmetry group of the cyclic cluster $C^{(A)}$. The group $\widetilde{G}^{(A)}$ is isomorphic to the factor group $G^{(A)}$. Both groups $\widetilde{G}^{(A)}$ and $G^{(A)}$ are homomorphic images of the space group G' . The translation group T_A is the kernel of this homomorphism. If the space group G' coincides with the space group G , the transformation (6.51) is called symmetric. In this case, the point symmetry of a cyclic cluster coincides with that of an infinite crystal. In our example, the cyclic cluster consisting of 9 primitive unit cells of hexagonal BN (see Fig. 6.1a) has the same point symmetry as the hexagonal BN in the one-layer model. The symmetric transformation (6.51) retains the point symmetry of the Bravais lattice, but it is compatible with a change of its type in the framework of the same crystalline system. As an example, one can consider the cyclic cluster defined by a crystallographic unit cell for face-centered cubic lattice (see Chap. 2) or the supercell of a hexagonal lattice, generated by the transformation with nondiagonal matrix $l = \begin{pmatrix} 2 & 1 \\ -1 & 1 \end{pmatrix}$, with $L = 3$. In the first case, the translation

vectors of the cubic cluster of 4 primitive unit cells ($l = \begin{pmatrix} -1 & 1 & 1 \\ 1 & -1 & 1 \\ 1 & 1 & -1 \end{pmatrix}$, $L = 4$)

form a simple cubic lattice. In the second case, the lattice of supercells remains hexagonal. The nonsymmetric transformation (6.51) leads to a cyclic cluster with the point-symmetry group F' that is lower than that of an infinite crystal. The smallest possible cyclic cluster $C^{(A)}$ is a primitive unit cell with the symmetry group $\widetilde{G}^{(a)}$ of the order n_F ($\widetilde{F}^{(a)} \leftrightarrow F$). The so-called main region of a crystal is also a cyclic cluster corresponding to the transformation (6.51) with very large $L = N_1 N_2 N_3$; it is assumed that there are N_i primitive unit cells in direction $\mathbf{a}_i$ ($i = 1, 2, 3$) (where N_i is a very large number). When the cyclic boundary conditions are introduced for the main region of a crystal, the translation group T_A consists of translations $\mathbf{A}_i = N_i \mathbf{a}_i$ ($i = 1, 2, 3$), that is, the transformation matrix l in (6.51) is assumed to be diagonal. Usually no attention is paid to the fact that the main region possesses the point symmetry of an infinite crystal only if the corresponding transformation (6.51) is symmetric. For example, the main region for a cubic crystal has to be defined with $N_1 = N_2 = N_3$. The space group G of the infinite crystal may be obtained as a limit of the symmetry groups of a sequence of increasing cyclic systems.

As is seen, the symmetry operations in the cyclic-cluster symmetry group are defined with the modified multiplication law modulo T_A . These groups were named by Stewart [289] “the symmetry groups of unit cells in solids” and interpreted as a new type of group being intermediate between point-symmetry groups of molecules

and space groups of infinite crystals. The irreducible representations of these groups are defined by those of space groups for the points of the BZ satisfying the condition $\exp(i\mathbf{k} \cdot \mathbf{A}_j) = 1$ where $\mathbf{A}_j$ are the translation vectors of the cyclic cluster as a whole. These points are given by (4.84) for $\mathbf{k} = \mathbf{0}$ and can be easily found. All the possible transformation matrices, given in Appendix A, can be used to generate the symmetric cyclic clusters of any of the 14 Bravais lattices. In the cyclic-cluster calculations, both the point and inner translation symmetry can be taken into account [290].

The CCM model allows real-space calculations (formally corresponding to the BZ center for the infinite crystal composed of the supercells). From this point of view, the cyclic cluster was termed a quasimolecular large unit cell [279] or a molecular unit cell [278].

The practical cyclic-cluster calculations for crystals were made by EHT, MR, and different ZDO methods. In these calculations, one has to take into account the multiplication law of the cyclic-cluster symmetry group. This requires the modifications (compared with molecules) of Fock matrix elements in the LCAO approximation. These modifications are considered in the next sections.

6.3.2 *Semiempirical LCAO Methods in Cyclic-Cluster Model*

In cyclic-cluster calculations, we return to the molecular level without the loss of the symmetry, replacing a whole crystal by one supercell (multiple of the primitive unit cell), applying to it PBC, and embedding a cyclic cluster in the Madelung field of the surrounding crystal. Instead of the system of coupled LCAO equations (4.57) for different wavevectors in the BZ, we have one equation to be solved in each iteration as in the case of molecules.

In EHT for crystals, the one-electron Hamiltonian and overlap integrals matrix elements (6.4) and (6.5) depend on wavevector $\mathbf{k}$ and are the sums over a direct lattice. The order M of the corresponding matrices H and S is equal to the number of AOs in the primitive unit cell.

In the CCM, the supercell is introduced so that the order of the matrices in the secular equation (6.4) is equal to $L \times M$, where L is defined in (6.51) and means the number of primitive cells in a supercell. The calculation is made only for $\mathbf{k} = \mathbf{0}$ so that instead of (6.4), we obtain the molecular-type secular equation

$$\det |H_{\mu\nu} - \varepsilon_i S_{\mu\nu}| = 0 \quad (6.58)$$

where μ, ν, i change from 1 to $L \times M$. The difference between the Hamiltonian and overlap matrices in (6.58) from the molecular analog (when the supercell atoms are taken as a free molecular cluster) is due to the introduction of PBC for the supercell chosen. Instead of lattice sums (6.5), we have now the matrix elements calculated for all $L \times M$ AOs of a supercell. PBC are taken into account by

modification of these matrix elements. To show this modification, let us consider a cyclic cluster B_9N_9 of the one-layer model of hexagonal boron nitride BN_{hex} , see Fig. 6.1. The primitive unit cell in this case contains one formula unit BN; the cyclic cluster chosen is formed by threefold increase in both translation vectors of the primitive unit cell. The central cyclic cluster and the nearest translated atoms are shown in Fig. 6.1. The primed B and N atoms are not included in the cyclic cluster explicitly but are translation equivalent (with the supercell translation vectors) to the corresponding nonprimed atoms inside the cyclic cluster. As was shown in Sect. 6.3.1, due to PBC introduction, the cyclic-cluster translations are multiplied *modulo* the translation group T_A of supercell as a whole (in our example this group consists of two supercell basic translations $A_1 = 3a_1, A_2 = 3a_2$, and all their combinations $A_n = \sum_{i=1}^2 n_i A_i$ with integer coefficients n_i). As a result, the matrix elements of H and S matrices are modified. The interactions between atoms in the supercell and those outside are then used to replace their weaker analog within the supercell [275]. For example, boron atom 1 interacts with nitrogen atoms 14 and 6 in the supercell as with the nearest neighbors because in atomic pairs 14–14', 6–6', two atoms are connected by the translation vectors of a cyclic cluster as a whole (see Fig. 6.1). Thus, we have no more “central” and “boundary” atoms in the cyclic cluster—for all of them the interactions with the nearest, next-nearest, and next-next-nearest neighbors are taken into account.

The cyclic cluster can be chosen in the form of the Wigner–Seitz unit cell (shown by the dotted line in Fig. 6.1 with the center at boron atom 1). A connection of the interaction range to these cell atoms was discussed in [291].

PBC introduction for the cyclic cluster chosen allows connection by of symmetry the MOs of the cyclic cluster with some COs of a whole crystal [287]. Let a perfect crystal be described in terms of supercells composed of L primitive unit cells. Correspondingly, the reduced (small) BZ of the supercell is a factor of L smaller than the original BZ of the primitive unit cell. If wavevectors in the original BZ are denoted by $\mathbf{K}$ and wavevectors in the reduced (small) BZ by $\mathbf{k}$, a calculation at a single $\mathbf{k}$ -point is equivalent to a calculation at a particular set of $\mathbf{K}$ -points satisfying relation (4.84) determined by the translation vectors A_n of the supercell chosen. This “folding back” of information was used to generate special points of BZ in the model of an infinite crystal (see Sect. 4.2.2) and also forms the basis of the cyclic-cluster model. When the whole crystal is replaced by a cyclic cluster, the $\mathbf{k}' = \mathbf{0}$ approximation in the reduced BZ is made and (4.84) can be written in the form:

$$\bar{\mathbf{K}}_t^{(0)} = \sum_j q_{tj} \mathbf{b}_j \quad (6.59)$$

where q_{tj} are integers, $\mathbf{b}_j$ are translation vectors of a reduced BZ and $\bar{\mathbf{K}}_t^{(0)}$ form the set of $\mathbf{K}$ -points of the original BZ folding down onto the $\mathbf{k} = 0$ point of a reduced BZ. Due to the relation $(A_i \mathbf{b}_j) = 2\pi\delta_{ij}$ between supercell translation vectors A_i , $i = 1, 2, 3$ and small BZ translation vectors $\mathbf{b}_j$, $j = 1, 2, 3$, (6.59) becomes equivalent to the condition

$$\exp(i\bar{\mathbf{K}}_l^{(0)} \mathbf{A}_j) = 1, \quad j = 1, 2, 3 \quad (6.60)$$

that has to be satisfied for those $\mathbf{K}$ -points of the original BZ that fold down on $\mathbf{k} = \mathbf{0}$ point of the reduced BZ.

In our example of a hexagonal lattice supercell with $L = 9$ (Fig. 6.1b), the relation (6.60) is satisfied for three points of the plane hexagonal BZ: $\Gamma(0, 0)$, $2P(1/3, 1/3)$, and $6G(1/3, 0)$ (the integer numbers mean the number of rays in the stars; the coordinates of stars representatives from the irreducible part of the BZ are given in brackets). These points formally become equivalent to the $\Gamma(\mathbf{k} = \mathbf{0})$ point of the primitive cell BZ [279].

Therefore, the cyclic-cluster energy level degeneration differs from that which would be for the corresponding free cluster of the same atoms. In the latter case, the point symmetry of the cluster is C_{3v} so that only the degeneracy of levels can be one or two (dimensions of irreps of point group C_{3v}). In the former case, the degeneracy of MOs remains at 1, 2 only at the Γ point of the BZ. The one-electron states at P and G points are 2-, 4-, and 6-times degenerate, respectively. It becomes clear when one takes into account that the space-group irrep dimension is the product of the dimension of the irrep of the wavevector point group (C_3 for P point, C_1 for G point) times the number of rays in wavevector star (2, 6 for P and G points, respectively, see Chap. 3). It is also necessary to take into account the time-inversion symmetry, making additional degeneracy for $\mathbf{k}$ and $-\mathbf{k}$ values of the wavevector.

What happens when the cyclic cluster is increased? Depending on its shape and size, different sets of $\mathbf{k}$ -points are reproduced, but in the EHT matrix elements, the number of interactions included (interaction radius) increases as the periodically reproduced atomic sites distance is defined by the translation vector of a cyclic cluster as a whole. It is important to reproduce in the cyclic-cluster calculations the states defining the bandgap. As the overlap matrix elements decay exponentially with the interatomic distance, one obtains the convergence of results with increasing cyclic cluster. Of course, this convergence is slower the more diffuse are the AOs in the basis. From band-structure calculations, it is known that for BN_{hex} in the one-layer model, the top of the valence band and the bottom of the conduction band are at the point P of the BZ reproduced in the cyclic cluster considered.

We note that the symmetry connection of crystal and cyclic-cluster one-electron states is defined only by the supercell choice and therefore does not depend on the method used in the Hamiltonian matrix-element calculations.

The EHT method is noniterative so that the results of CCM application depend only on the overlap interaction radius. The more complicated situation takes place in iterative Mulliken–Rüdenberg and self-consistent ZDO methods. In these methods for crystals, the atomic charges or the whole of the density matrix are calculated by summation over $\mathbf{k}$ points in the BZ and recalculated at each iteration step. The direct lattice summations have to be made in the surviving integrals calculation before the iteration procedure. However, when the nonlocal exchange is taken into account (as is done in the ZDO methods), the balance between direct lattice and BZ summations has to be ensured. This balance is automatically ensured in

cyclic-cluster calculations as was shown in Chap. 4. Therefore, in iterative MR and self-consistent ZDO methods, the increase of the cyclic cluster ensures increasing accuracy in the direct lattice and BZ summation simultaneously. This advantage of CCM is in many cases underestimated.

In the MR method, the matrix elements of a cyclic cluster are obtained from those for the crystal, taking $\mathbf{k} = \mathbf{0}$ in (6.26). The modification of matrix elements due to PBC introduction has to be introduced in overlap and kinetic energy integral calculation. The latter are expressed through overlap integrals so that there are no principal differences in the EHT and MR methods in the matrix-element modification, ensuring periodicity of the cluster chosen. The only difference is connected with the iterative procedure of atomic charge and configuration self-consistency in the MR method, requiring the calculation of diagonal elements of the density matrix. In this calculation, the summation over occupied MOs of the cyclic cluster is made that is equivalent to summation over those $\mathbf{K}$ -points of the original BZ that satisfy relation (6.60). The diagonal elements of the MR method Hamiltonian are corrected by the point-charge (Madelung) field of the surrounding crystal acting on cyclic-cluster atoms; see (6.26). In fact, the embedded cyclic cluster is considered. For ionic systems, such a correction of CCM is necessary both in the ZDO and SINDO methods [291, 292]. In CCM, the iterative calculations of the atomic charges are used at any step of the iterative procedure to recalculate the Madelung energy for all atoms of a cyclic cluster, and at the next step, the atomic charges are recalculated with the matrix elements corrected by a recalculated Madelung energy.

Within the $\mathbf{k} = \mathbf{0}$ approximation, the CNDO Hamiltonian for the supercell becomes

$$F_{\mu\mu}(\mathbf{0}) = U_{\mu\mu} + Z_M \gamma_{MM}^{00} + \sum_N \left(\frac{1}{L'} \sum_{\mathbf{k}'} P_N(\mathbf{k}') - Z_N \right) \sum_{n=0}^{L'-1} \gamma_{MN}^{0n} \\ + \sum_{n=0}^{L'-1} \beta_M^0 (S_{\mu\mu}^{0n} - \delta_{0n}) - \frac{1}{2L'} \sum_{n=0}^{L'-1} \sum_{\mathbf{k}'} P_{\mu\mu}(\mathbf{k}') \exp(-i\mathbf{k}' \mathbf{R}_n) \gamma_{MM}^{0n} \quad (6.61)$$

$$F_{\mu\nu}(\mathbf{0}) = \sum_{n=0}^{L'-1} \beta_{MN}^0 S_{\mu\nu}^{0n} - \frac{1}{2L'} \sum_{n=0}^{L'-1} \sum_{\mathbf{k}'} P_{\mu\nu}(\mathbf{k}') \exp(-i\mathbf{k}' \mathbf{R}_n) \gamma_{MN}^{0n} \quad (6.62)$$

where L' is the number of supercells in the main region of a crystal and $\mathbf{k}'$ -summation is made over the reduced BZ.

A calculation performed solely at the $\Gamma(\mathbf{k}' = \mathbf{0})$ point of the supercell BZ would become entirely equivalent to special $\mathbf{K}$ -points (6.59) calculation if all the direct lattice summations were made over the whole crystal. However, in CCM, the interaction range depends on the cyclic-cluster size. To determine the $\mathbf{k}' = \mathbf{0}$ Fock matrix elements, we need the full $\mathbf{k}'$ dependence of the supercell

density matrices $P_{\mu\nu}(\mathbf{k}')$, see (6.61) and (6.62). Meanwhile, each iteration in a cyclic-cluster calculation only provides the eigenvector coefficients $C_{i\mu}(\mathbf{0})$ at $\mathbf{k}' = \mathbf{0}$, and hence only $P_{\mu\nu}(\mathbf{0})$. Therefore, it is necessary to relate the reduced BZ integrals over the fully $\mathbf{k}'$ -dependent density matrices, namely, $\sum_{\mathbf{k}'} P_N(\mathbf{k}')$ and $\sum_{\mathbf{k}'} P_{\mu\nu}(\mathbf{k}') \exp(-i\mathbf{k}' \mathbf{R}_n)$ to $P_N(\mathbf{0})$ and $P_{\mu\nu}(\mathbf{0})$, respectively [270]. For sufficiently large supercells, all the values of $\mathbf{k}'$ in the reduced BZ will lie near $\mathbf{k}' = \mathbf{0}$ so that it should be valid to ignore the effect of the phase factor and use the fact that the reduced BZ is spanned by L $\mathbf{k}$ -points to obtain

$$\frac{1}{L'} \sum_{\mathbf{k}'} P_{\mu\nu} \exp(-i\mathbf{k}' \mathbf{R}_n) \rightarrow P_{\mu\nu}(\mathbf{0}) \quad (6.63)$$

Simple substitution of (6.63) into (6.61) and (6.62) would introduce divergent lattice sums of γ_{MN}^{0n} integrals. Therefore, a distance-dependent modulating function $\omega(R_{MN}^{0n})$ was introduced [270] such that

$$\frac{1}{L'} \sum_{\mathbf{k}'} P_{\mu\nu}(\mathbf{k}') \exp(-i\mathbf{k}' \mathbf{R}_n) = \omega(R_{MN}^{0n}) P_{\mu\nu}(\mathbf{0}) \quad (6.64)$$

(orbital μ on atom M is in cell 0, and orbital ν is on atom N in cell n).

To find an approximate form of this modulating function, a tight-binding description of a one-dimensional chain of atoms possessing one atom per primitive unit cell and two orbitals per atom was studied [270]. The $\text{sinc}^2(\frac{\pi}{a} R_{MN}^{0n})$ function found was simply extended to the three-dimensional cubic lattice case. Unfortunately, the form of this modulating function depends on the direct lattice of supercells, and its extension to noncubic lattices is nontrivial.

In some cases, the modulating function $\omega(R_{MN}^{0n})$ is taken as the simple step function:

$$\omega(R_{MN}^{0n}) = \begin{cases} 1 & \text{if } R_{MN}^{0n} \leq R_c \\ 0 & \text{if } R_{MN}^{0n} > R_c \end{cases} \quad (6.65)$$

where the exchange cutoff radius R_c in (6.65) was a variable parameter or taken intuitively to be about a half of the cyclic-cluster smallest translation vector length. As was shown in Sect. 4.3.3, the modulating (weighting)-function explicit form (4.157) can be found in the interpolation procedure for constructing an approximate density matrix. The modulating step function suggested in (4.157) is easily applied to any type of lattice and was incorporated into both HF and CNDO cyclic-cluster calculations [67]. It was shown that the exchange-interaction range should be chosen such that the corresponding sphere of radius R_c differs only slightly from the Wigner–Seitz supercell, corresponding to the cyclic cluster. This gave a theoretical background to the former intuitive choice (6.65) of the exchange-interaction radius R_c .

Cyclic-cluster CNDO Hamiltonian matrix elements may be written in the following form:

$$F_{\mu\mu}(\mathbf{0}) = U_{\mu\mu} + Z_M \gamma_{MM}^{00} + \sum_N \sum_{n=0}^{L'-1} \sum_{v \in N} (P_{\mu\mu}(\mathbf{0}) - Z_N) \gamma_{MN}^{0n} \\ + \sum_{n=0}^{L'-1} \beta_M^0 S_{\mu\mu}^{0n} - \frac{1}{2} \sum_{n=0}^{L'-1} P_{\mu\mu}(\mathbf{0}) \omega(R_{MN}^{0n}) \gamma_{MM}^{0n} \quad (6.66)$$

$$F_{\mu\nu}(\mathbf{0}) = \sum_{n=0}^{L'-1} \beta_{MN}^0 S_{\mu\nu}^{0n} - \frac{1}{2} \sum_{n=0}^{L'-1} P_{\mu\nu}(\mathbf{0}) \omega(R_{MN}^{0n}) \gamma_{MN}^{0n} \quad (6.67)$$

Comparing CCM Hamiltonian matrix elements (6.66) and (6.67) with those for a free molecule, Eqs. (6.33)–(6.35), one can see the differences. Equations (6.66) and (6.67) formally include summation over the main region of a crystal composed of the equivalent supercells. The lattice sums containing overlap integrals are truncated for a cyclic cluster in the CNDO method in the same way as is done in the EHT and MR methods. For the Coulomb interaction sums (third item in (6.66)), the Ewald method can be used to calculate the Madelung energy of a crystal surrounding the cyclic cluster. The modulating function $\omega(R_{MN}^{0n})$ ensures the truncation of the diverging lattice sums appearing in the nonlocal exchange interactions (last items in (6.66) and (6.67)).

CCM has been implemented in various ZDO methods: CNDO–INDO [266, 267, 270, 293–300], MINDO/3 [301], MNDO [261], and NDDO(AM1, PM3), [302]. All the semiempirical methods stand or fall by their parameter set. The ZDO method parameter sets suitable for molecular calculations will not necessarily be suitable for the solid state. The parametrization scheme may be dependent on the chemical bonding in the crystal (different sets of parameters are suitable for ionic and covalent crystals), introducing additional difficulties.

The main ZDO parameters for each orbital type are the orbital exponent ζ entering the radial part of Slater-type AOs, the diagonal matrix elements $U_{\mu\mu}$ of the interaction of an electron-occupying AO χ_μ with its own core expressed through electronegativity $E_{\text{neg}}^M = -1/2(I_\mu + A_\mu)$ of this AO, and the resonance integrals β depending only on the atom type. Additional parameters appear in the matrix elements of an interaction of an electron on the μ th AO belonging to atom M with the core of another atom N , [303]:

$$V_{\mu N} = Z_N \left\{ \frac{1}{R_{MN}} + \left[(\mu\mu|vv) - \frac{1}{R_{MN}} \right] \exp(-\alpha_N R_{MN}) \right\} \quad (6.68)$$

where R_{MN} is the distance between M and N , Z_N is the core charge of atom N and α_N is an adjustable parameter characterizing the nonpoint nature of the atom N core. AOs χ_μ and χ_ν belong to atoms M and N , respectively; the two-center Coulomb integral $(\mu\mu|vv)$ may be calculated with STOs or considered as γ_{MN} depending only on atom types. The detailed discussion of parameter choice in CCM ZDO methods

can be found for different types of crystalline solids: ionic crystals of alkali halides [290,294,304,305] and simple oxides MgO,CaO [303], covalent and partly covalent semiconductors [266,283,300,302,306,307], and crystalline oxides with different structure [308], including high- T_c superconductors [308].

In the next section, we discuss MSINDO semiempirical and HF nonempirical methods implementation of CCM for the calculation of bulk properties of rutile crystal. The efficiency of the MSINDO method will be demonstrated that gives reasonable agreement with the results of HF calculations and at the same time is essentially simpler in practical realization.

6.3.3 Implementation of the Cyclic-Cluster Model in MSINDO and Hartree–Fock LCAO Methods

The cyclic-cluster approach was implemented in the semiempirical SCF–MO method SINDO1 [309] and its recent modification MSINDO [291] and has been successfully applied for bulk and surface properties of oxides [292,310].

The underlying strategy of the CCM implementation in MSINDO was to start from a molecular system and to introduce PBC in such a way that both local point symmetry and stoichiometry of the system are conserved. Within this approach, the local environment of each cyclic-cluster atom is replaced by that of a fictitious cyclic arrangement. A cluster of n atoms in one dimension is treated in the same way as a cyclic arrangement of the same number of atoms on a ring. Two- and three-dimensional systems are treated as arrangements on a torus and a hypertorus, respectively. All interactions for each atom M are then calculated within an interaction region around that atom, corresponding to its Wigner–Seitz cell (WSC). For two-center integrals (overlap, nuclear attraction, electron repulsion) between the M atom of the interaction region and atoms at the boundaries of its WSC [291], weighting factors are used to retain the proper symmetry. In this approach, the cyclicity and summation regions are the same and not dependent on integral thresholds as for periodic LCAO methods [21]. Long-range Coulomb interactions have been taken into account by additional finite point-charge fields outside the cyclic cluster [292]. A scheme for the calculation of analytical gradients has been developed for structure optimization of cyclic clusters [291].

In MSINDO, only two-center two-electron integrals of the form $(\mu M \mu M | \nu N \nu N)$ are taken into account. Atomic orbitals χ_μ and χ_ν are taken as s -type functions. Therefore, these integrals have no angular dependence, and an averaging over integrals between different atoms on the same radius around the considered atom causes no problems.

In MSINDO, also two-center one-electron integrals are replaced by empirical formulas that do not contain any angular dependence so that the two-center elements of the Fock matrix have the following form [239]:

$$F_{\mu\nu} = H_{\mu\nu} + P_{\mu\nu}(\mu\mu|\nu\nu) = \Delta H_{\mu\nu} + L_{\mu\nu} + P_{\mu\nu}(\mu\mu|\nu\nu) \quad (\mu \in M, \nu \in N) \quad (6.69)$$

with the two parameterized empirical functions

$$\begin{aligned}\Delta H_{\mu\nu} &= \frac{1}{4} (K_M + K_N) S_{\mu\nu} (f_M h_{\mu\mu} + f_N h_{\nu\nu}), \quad f_M = 1 - \exp(-\alpha_M R_{MN}) \\ L_{\mu\nu} &= -\frac{1}{2} (\zeta_\mu^2 + \zeta_\nu^2) \frac{S_{\mu\nu}(1 - S_{\mu\nu})}{1 + 1/2(\zeta_\mu + \zeta_\nu)R_{MN}}\end{aligned}\quad (6.70)$$

where ζ_μ, ζ_ν are orbital exponents and K_M, K_N , and α_M are empirical parameters optimized for a given set of reference molecules. In CCM calculations, these matrix elements remain unchanged when atom N is in the inner part of the interaction region of atom M . In the case that N is on the border of the interaction region around M , the contributions from all $n_{MN'}$ atoms N' that are translationally equivalent to N and appear at the same radius are summed up into one matrix element with weighting coefficient [291]:

$$\begin{aligned}H_{\mu\nu} &= \sum_{N'}^{\text{equiv}} \omega_{MN'} H_{\mu\nu'}, \quad \nu' \in N \\ G_{\mu\nu} &= \sum_{N'}^{\text{equiv}} \omega_{MN'} (\mu\mu|v'v')\end{aligned}\quad (6.71)$$

The construction of the Fock matrix and the SCF procedure to obtain a converged density matrix of the cyclic system is essentially identical to the molecular case. The only extension is the inclusion of an external point-charge field that is added to the diagonal terms of F . As the calculations for the cyclic clusters are performed in real space, no Bloch functions are used as the basis set. This strategy makes a direct comparison between calculations for free and cyclic clusters possible. Because of the quadratic increase of the number of two-center integrals with the number of cluster atoms, a special technique can be used to reduce the computational effort [311]. This technique is based on the sorting of the interatomic distances because equal atom pairs with the same distance have identical integrals in a local coordinate system. With this technique, the number of calculated integrals can be decreased by a factor of 1,000 or more. All features available in the molecular version of MSINDO, for example, configuration interaction, geometry optimization, or vibration analysis, can also be used for the cyclic clusters. This also includes the treatment of charged systems that are generally difficult to treat with periodic methods.

Interactions of an ion M with ions N'' at a distance beyond the borders of the WSC will decrease rapidly with increasing interatomic distance in covalent systems. This does not hold for ionic systems, since Coulomb-type interactions fall off slowly. If the ions N'' are approximated as point charges with a net charge q , the Madelung potential due to these charges, which can be calculated by the Ewald

summation technique as shown in [292], will modify the Fock matrix and the total energy in the following way:

$$F^{\text{MAD}}(P) = F(P) + V^{\text{MAD}}(P) \quad (6.72)$$

$$E_{\text{tot}} = \frac{1}{2} \text{Tr} [P(H + F^{\text{MAD}})] + V_{NN} + E^{\text{MAD}} \quad (6.73)$$

Here, F denotes the Fock matrix, F^{MAD} the Madelung-corrected Fock matrix, P the density matrix, H the core Hamiltonian matrix, E_{tot} the total energy of the system, and V_{NN} the nuclear repulsion term. The terms $V^{\text{MAD}}(P)$ and E^{MAD} denote the Madelung correction of the Fock matrix and of the nuclear repulsion, respectively. Due to the application of the ZDO approximation in MSINDO, $V^{\text{MAD}}(P)$ is a diagonal matrix,

$$V_{\mu M \mu M}^{\text{MAD}} = \Phi_{mD}(\bar{d}_M) - \sum_{N''} \omega_{MN''} \frac{q_{N''}}{|\bar{d}_M - \bar{d}_{N''}|} \quad (6.74)$$

$$E^{\text{MAD}} = \frac{1}{2} \sum_M Z_M^* \left[\Phi_{mD}(\bar{d}_M) - \sum_{N''} \omega_{MN''} \frac{q_{N''}}{|\bar{d}_M - \bar{d}_{N''}|} \right] \quad (6.75)$$

Z_M^* is the effective nuclear charge of atom M . The corrections are implemented in a self-consistent manner, since the net charges $q_{N''}$ are calculated from the cluster density matrix P using a Löwdin population analysis. The electrostatic interactions of the ion M with the ions in its WSC must be subtracted from the Madelung potential Φ_{mD} , because these interactions are already considered in the unmodified Fock matrix $F(P)$. To avoid double counting of interactions, the factor 1/2 is introduced in (6.75).

It has to be mentioned that the simple procedure used in CCM MSINDO of an averaging of two-center integrals between the central atom of the interaction region and atoms at the boundaries of its WSC is not possible for *ab initio* Hartree–Fock methods due to the presence of three- and four-center integrals.

The implementation of the CCM in the HF LCAO method is based on the use of the idempotency property of a one-electron density matrix (DM) of crystalline systems [95]. The underlying strategy in this case was to start from a periodic system and to make small modifications in the corresponding LCAO computer codes. It has to be mentioned that the CCM realization in PW basis seems to be impossible as the interaction region in this case cannot be defined.

The idempotency of the DM is a consequence of the orthonormality of the one-electron Bloch functions that are the basis of the crystalline orbitals. In the CCM, the DM has to be idempotent when a one-determinant wavefunction is used and convergence with cluster size is achieved. The infinite DM of a solid formally does not have this property, but the infinite solid itself is modeled by a very large cyclic cluster describing the main region of the crystal when Born–von Karman PBC are introduced to ensure macroscopic periodicity of a crystal model. In Sect. 4.3.3,

the CCM of the infinite crystal was deduced from the study of the approximate DM (4.164). The supercell corresponding to the cyclic cluster under consideration was taken as the Wigner–Seitz supercell; to have the proper point symmetry, the weighting function (4.165) was introduced. Defining an atomic covalence as the sum of Wiberg indices for an atom in the cyclic cluster or all the other atoms of a crystal the relation (4.140) was obtained. This relation means that the atomic covalence in a cyclic cluster may be calculated as a lattice sum $C_M^{(2)}$ of Wiberg indices and as an expression $C_M^{(1)}$, containing only those DM elements that refer to atom M :

$$\begin{aligned} \sum_M C_M^{(2)} &= \sum_M \sum_{M \neq N} \omega_N(\bar{R}_N) W_{MN}(\bar{R}_n) + \sum_M W_{MM}(0) = N_e^C \\ \sum_M C_M^{(1)} &= \sum_M \left(2 \sum_{\mu \in M} P_{\mu\mu}^L(0) - W_{MM}(0) \right) = N_e \end{aligned} \quad (6.76)$$

where N_e^C , N_e is the number of electrons in the primitive unit cell. For each cyclic cluster, there are certain weighting coefficients $\omega_N(\bar{R}_N)$ of neighbor atoms in spheres around atom M . For the inner atoms of a cyclic cluster, $\omega_N = 1$, while for border atoms, $\omega_N < 1$.

Relation (6.76) provides a simple way to check the idempotency property of the DM. Therefore, it can be used to implement the CCM in HF LCAO calculations.

This implementation requires simple modifications in the property part of the CRYSTAL program [21]. A Löwdin population analysis is introduced for self-consistent DM and the bond-order sums are calculated for atoms of the crystal. The lattice summation in (6.76) is made over the same part of the lattice that has been used in the integrals calculation for the self-consistent procedure (the lattice summation field is defined by the most severe tolerance used in the two-electron exchange integrals calculation).

In order to receive results for a cyclic cluster, relation (6.76) is checked for different choices of tolerances in the integrals calculations and Q sets of wavevectors in the BZ, corresponding to those $\mathbf{K}$ -sets that satisfy (6.60). The implementation of a cyclic cluster for perfect crystals is realized in most cases by using the primitive unit cell and taking into account that the *cyclicality field* of the DM is defined by the choice of Q. The implementation of the CCM in HF LCAO calculations is demonstrated for the rutile structure.

The tetragonal rutile structure belongs to space group $P4_2/mnm(D_{4h}^{14})$ and contains two TiO_2 units per cell. The two Ti atoms are located at the Wyckoff $2a$ sites $(0, 0, 0)$ and $(1/2, 1/2, 1/2)$ with D_{2h} site symmetry, while the four O atoms are located at the $4f$ sites $\pm(u, u, 0)$ and $\pm(u + 1/2, 1/2 - u, 1/2)$ with site symmetry C_{2v} (see Sect. 2.2.3). The primitive unit cell of rutile is illustrated in Fig. 6.2. Each Ti atom is surrounded by a slightly distorted octahedron of O atoms with two different Ti–O distances. In connection with the cyclic-cluster choice, it is useful to label the atoms surrounding $\text{Ti}_{(1)}$ and $\text{O}_{(3)}$ in the primitive cell (000) by the translation vectors of the corresponding unit cells (see Fig. 6.2). From Fig. 6.2,

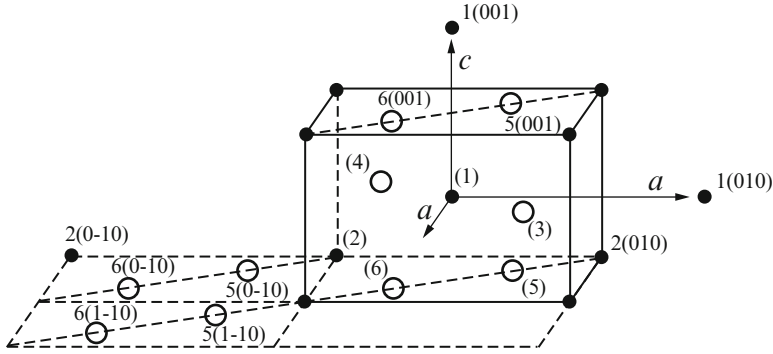


Fig. 6.2 Labeling of atoms in the rutile bulk unit cell; selected atoms of neighboring unit cells are also given

it is seen that the inclusion of all nearest neighbors for a Ti atom requires at least a cyclic cluster with translation vectors $\mathbf{a}_1(0, 0, a)$, $\mathbf{a}_2(0, a, 0)$, and $2\mathbf{a}_3(0, 0, 2c)$. The smallest cyclic cluster that contains the nearest neighbors to an O atom is formed by translation vectors $2\mathbf{a}_1(2a, 0, 0)$, $2\mathbf{a}_2(0, 2a, 0)$, and $2\mathbf{a}_3(0, 0, 2c)$. For simple tetragonal lattices the symmetric supercells can be made in four different ways while maintaining tetragonal symmetry:

1. By simple extension of translation vectors ($n_1\mathbf{a}_1, n_2\mathbf{a}_2, n_3\mathbf{a}_3$). The corresponding transformation matrix is given in Table 6.1 at the bottom of the first column.
2. By rotation of vectors $\mathbf{a}_1$ and $\mathbf{a}_2$ by 45° in their plane and extension of the vector. The transformation matrix is given in the second column of Table 6.1.
3. By changing from a simple to a body-centered tetragonal lattice. This can be achieved in two different ways. The corresponding transformation matrices are given in columns 3 and 4 of Table 6.3.

In Table 6.3, cyclic clusters representing the rutile bulk structure are given that are generated from the primitive bulk unit cell by applying the above-mentioned four types of LUC transformations. The cluster size was restricted to $L = 24$ (144 atoms).

As it was noted in Sect. 6.3.2, CCM allows us to connect by symmetry the MOs of cyclic cluster with those COs of a whole crystal for which (6.60) is satisfied.

The BZ for the simple tetragonal lattice was shown in Fig. 3.7. The $\mathbf{K}$ symmetry points and $\mathbf{K}$ -points in symmetry lines (in units of the basic translation vectors of the reciprocal simple tetragonal lattice) are the following (for lines of symmetry, the parameter $p < 1$ has to be introduced): symmetry points $\Gamma(0, 0, 0)$, $M(\frac{1}{2}, \frac{1}{2}, 0)$, $Z(0, 0, \frac{1}{2})$, $A(\frac{1}{2}, \frac{1}{2}, \frac{1}{2})$, $2X(0, \frac{1}{2}, 0)$, $2R(0, \frac{1}{2}, \frac{1}{2})$; symmetry lines $\Gamma - X = \Delta(0, p, 0)$, $\Gamma - M = \Sigma(p, p, 0)$, $\Gamma - Z = \Lambda(0, 0, p)$, $M - X = Y(p, \frac{1}{2}, 0)$, $A - R = T(p, \frac{1}{2}, \frac{1}{2})$, $Z - A = S(p, p, \frac{1}{2})$, $M - A = V(\frac{1}{2}, \frac{1}{2}, p)$, $Z - R = U(0, p, \frac{1}{2})$, $X - R = W(0, \frac{1}{2}, p)$, $\Gamma - A = \varepsilon(p, p, p)$.

Table 6.3 Cyclic clusters used for the representation of the rutile bulk, special point (SP)-set, and its accuracy J

CL ^a ,1			CL ^a ,2			CL ^a ,3			CL ^a ,4		
n_1	n_2	Cluster	SP-set	J	Cluster	SP-set	J	Cluster	SP-set	J	Cluster
1	1				C2.2	Γ, Z	1	C2.3	Γ, A	3	C4.4
1	2	C2.1	Γ, M	2	C4.2	Γ, M, A, Z	4	C4.3	$\Gamma, Z, 2V$	5	$\Gamma, M, Z, A,$ $4W(p = \frac{1}{4})$
2	1	C4.1	$\Gamma, M, 2X$	1	C8.2	$\Gamma, M, 2X,$ $4\Sigma(p = \frac{1}{4})$	1	C8.3	$\Gamma, M, 2X,$ $4S(p = \frac{1}{4})$	4	$\Gamma, M, 2X,$ $4\Sigma, 4U, 4T(p = \frac{1}{4})$
2	2	C8.1	$\Gamma, M, Z,$ $A, 2X, 2R$	4	C16.2	$\Gamma, M, Z,$ $A, 2X, 2R,$ $4\Sigma, 4S(p = \frac{1}{4})$	4	C16.3	$A, 2R,$ $8\epsilon(p = \frac{1}{4})$	15	
2	3	C12.1	$\Gamma, M, 2X,$ $2A, 2V,$ $2W(p = \frac{1}{3})$	9	C24.2	$\Gamma, M, 2X,$ $2V, 2A, 4W,$ $4\Sigma(p = \frac{1}{4}), 8(\frac{1}{4}, \frac{1}{4}, \frac{1}{3})$	9	C24.3	$2V, 2A, 4W,$ $4S(p = \frac{1}{4}),$ $8(\frac{1}{4}, \frac{1}{4}, \frac{1}{6})$	19	
2	4	C16.1	$\Gamma, M, 2X,$ $Z, A, 2R, 2A,$ $2V, 4W(p = \frac{1}{4})$	10							
		$L = n_1^2 n_2 = \begin{vmatrix} n_1 & 0 & 0 \\ 0 & n_1 & 0 \\ 0 & 0 & n_2 \end{vmatrix}$		$L = 2n_1^2 n_2 = \begin{vmatrix} n_1 & -n_1 & 0 \\ n_1 & n_1 & 0 \\ 0 & 0 & n_2 \end{vmatrix}$		$L = 2n_1^2 n_2 = \begin{vmatrix} 0 & n_1 & n_2 \\ n_1 & 0 & n_2 \\ n_1 & n_1 & 0 \end{vmatrix}$		$L = 4n_1^2 n_2 = \begin{vmatrix} -n_1 & n_1 & n_2 \\ n_1 & -n_1 & n_2 \\ n_1 & n_1 & -n_2 \end{vmatrix}$			

^a L is the number of primitive unit cells in the large unit cell defining the cyclic cluster. The number m in CL $_{m,m}$ defines the choice of the corresponding transformation matrix given at the bottom of each column

In Table 6.3, K -point sets of the primitive cell BZ satisfying (6.60) and folding down on the $\mathbf{k} = \mathbf{0}$ point of the reduced BZ are given. The interaction region in CCM may be defined by WSC around each atom of a cyclic cluster or by the number J of spheres of direct lattice translation vectors $\mathbf{A}_n$ with smallest nonzero length, also given in Table 6.3. To implement CCM into the HF LCAO calculations [95], the periodic crystalline-orbital program CRYSTAL95 [312] was used with the modifications [92] that allow the DM idempotency (6.76) to be checked. In rutile TiO_2 calculations, the AO bases, lattice parameters, and effective core potentials were taken to be the same as those used in [313] to calculate the optimized lattice parameters. In the CRYSTAL code [21], the lattice sums of the integrals are truncated when the integrals values are smaller than 10^{-t_i} . The tolerances t_i ($i = 1 - 5$) define the accuracy of the lattice sum calculation. The band-structure calculations using the primitive unit cell of the rutile, the tolerances $t_1 = t_2 = t_3 = t_4 = 6, t_5 = 12$ (the latter is used for exchange interactions), and shrinking factor IS = 6 (216 $\mathbf{k}$ -points of $6 \times 6 \times 6$ Monkhorst–Pack special points in the BZ) ensure the converged results for the total energy per primitive cell, top of the valence band, and Löwdin charge on the Ti atom (-69.7758 a.u., -0.3028 a.u., and $q = 1.73$, respectively). The cyclic-cluster calculations were performed using the SUPERCELL option of CRYSTAL95 and setting the shrinking factors IS to unity (corresponding to the $\mathbf{k} = 0$ point in the BZ), defining the DM cyclicity region as the cyclic-cluster region itself. For the calculation of the total number of electrons per primitive cell, (6.76) can be used. For each cyclic cluster, there are certain weighting coefficients of neighbor atoms in spheres i around $\text{Ti}(\omega_{\text{Ti}}(i))$ and $\text{O}(\omega_{\text{O}}(i))$. At the same time, the above-mentioned tolerance t_5 defines the interaction radius for the exchange-integral truncation. For the given structural parameters and basis sets, this radius is $8.16 \text{ \AA}$ around a Ti atom and $7.84 \text{ \AA}$ around an O atom, respectively (for rutile TiO_2 with the optimized structures parameters $a = 4.555 \text{ \AA}$, $c = 2.998 \text{ \AA}$, $u = 0.306$). The total number of electrons per unit cell N_e within the interaction radius calculated by summing bond orders over spheres i , containing a total number $N(i)$ of atoms as given in the second line of Table 6.4. An analysis of Table 6.4 allows a cyclic cluster of relatively small size to be chosen in such a way that it still reproduces bulk properties with reasonable accuracy.

For the small-size clusters ($L = 4, 8$), the imbalance of the cyclicity region and the interaction radius causes a huge difference between N_e^C and N_e^s as the sum of bond orders inside the interaction radius includes the neighboring cyclic clusters around the central cyclic cluster. The PBCs force atoms outside the central cyclic cluster to be equivalent to the corresponding atoms inside the cluster. At the same time, the summation of bond orders inside a *cyclicity region* gives N_e^C values that are largely model-size independent, as the DM is calculated for the cyclic cluster under consideration.

From Table 6.4, one concludes also that even for the same size L of a cyclic cluster, the difference of the calculated properties $E_{\text{tot}}, \varepsilon_{\text{top}}$, and atomic charges q strongly depends on the “compactness” of a cluster. The compactness is defined by the number of spheres i of neighboring atoms with $\omega(i) = 1$ inside the

Table 6.4 Results of HF LCAO calculations of cyclic clusters for bulk rutile. Quality J , the difference of the total energy ΔE and the energy of the valence band top $\Delta\epsilon$ (a.u.) with respect to the largest cluster C216.1, total number of electrons per unit cell calculated with (6.76) within the corresponding cyclic cluster (N_e^C) and within the interaction radius defined by the integral thresholds (N_e^S), weighting coefficients of neighboring atoms in spheres i around Ti ($\omega_{Ti}(i)$) and O ($\omega_O(i)$), total number of atoms $N(i)$ in sphere i , Löwdin charge q_{Ti} on Ti

Cluster	J	ΔE	$\Delta\epsilon$	N_e^C	Spheres i $N(i)$	$\omega_{Ti}(i)$	$\omega_O(i)$	q_{Ti}
CL4.1	1	-4.4041	-0.2856	63.91	245.80	$\frac{1}{2}$ 10 1 $\frac{1}{2}$ 0	$\frac{1}{2}$ 11 $\frac{1}{2}$ 0 11 0 0 1	1.97
CL4.2	4	-0.0302	-0.0136	63.85	199.57	1 $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$	1 1 1 $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ 0	1.60
CL4.3	5	-0.0138	-0.0134	63.89	185.90	1 1 1 $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ 1	1 1 1 1 $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ 1 0	1.60
CL4.4	4	-0.0248	-0.0170	63.73	248.79	1 1 $\frac{1}{2}$ 1 $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$	1 1 1 1 $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$	1.68
CL8.1 ^a	4	-0.0167	-0.0127	63.77	111.32	1 1 1 1 $\frac{1}{2}$	1 1 1 1 $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ 1	1.69
CL8.2	1	-4.4048	-0.2854	63.92	241.76	$\frac{1}{2}$ 10 1 $\frac{1}{2}$ 0	$\frac{1}{2}$ 11 $\frac{1}{2}$ 0 $\frac{1}{2}$ $\frac{1}{2}$ 0 0 1	1.97
CL8.3	4	-0.0183	-0.0124	63.74	108.95	1 1 $\frac{1}{2}$ 1 $\frac{1}{2}$ $\frac{1}{2}$	1 1 1 1 $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ 1	1.69
CL8.4	8	-0.0022	-0.0040	63.81	74.66	1 1 1 1 1 1 1 1 1	1 1 1 1 1 1 1 1 1 1	1.72
CL12.1	9	0.0014	-0.0001	63.77	70.17	1 1 1 1 1 1 1 1 1	1 1 1 1 1 1 1 1 1 1	1.73
CL16.1	10	0.0010	-0.0003	63.79	67.04	1 1 1 1 1 1 1 1 1 1	1 1 1 1 1 1 1 1 1 1	1.73
CL16.2	4	-0.0178	-0.0125	63.76	108.14	1 1 $\frac{1}{2}$ 1 $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$	1 1 1 $\frac{1}{2}$ 1 $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ 1	1.69
CL16.3	15	0.0018	-0.0002	63.83	63.86	1 1 1 1 1 1 1 1 1 1	1 1 1 1 1 1 1 1 1 1	1.73
CL16.4	4	-0.0178	-0.0125	63.75	108.15	1 1 $\frac{1}{2}$ 1 $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$	1 1 1 $\frac{1}{2}$ 1 $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ 1	1.69
CL24.2	9	0.0014	-0.0001	63.78	66.94	1 1 1 1 1 1 1 1 1	1 1 1 1 1 1 1 1 1 1	1.73
CL24.3	19	0.0005	-0.0006	63.80	63.80	1 1 1 1 1 1 1 1 1	1 1 1 1 1 1 1 1 1 1	1.73
CL27.1 ^a	9	0.0008	0.0005	63.79	66.93	1 1 1 1 1 1 1 1 1	1 1 1 1 1 1 1 1 1 1	1.73
CL64.1 ^a	18	0.0002	-0.0002	63.80	63.80	1 1 1 1 1 1 1 1 1	1 1 1 1 1 1 1 1 1 1	1.73
CL216.1 ^a	33	0.0000	0.0000	63.79	63.79	1 1 1 1 1 1 1 1 1	1 1 1 1 1 1 1 1 1 1	1.73

^aBand calculations (the shrinking factors are 2, 3, 4, 6 for CL8.1, CL27.1, CL64.1, and CL216.1, respectively)

Table 6.5 Effect of integral thresholds on calculated properties of cyclic clusters CL12.1 and CL16.3; total energy E and top of valence band ϵ (a.u.), Löwdin charge q_{Ti} of Ti, total number of electrons per unit cell calculated using (6.76) within the corresponding cyclic cluster (N_e^C) and within the interaction radius defined by the integral thresholds (N_e^S)

Cluster	Integral thresholds	E	ϵ	q_{Ti}	N_e^C	N_e^S
CL12.1	6 12	-69.7744	-0.3029	1.73	63.77	70.17
	6 9	-69.7747	-0.3032	1.73	63.81	64.01
	6 9 ^a	-69.7760	-0.3029	1.73	63.74	63.75
	6 8	-69.7746	-0.3034	1.73	63.75	63.94
	6 8 ^a	-69.7758	-0.3028	1.73	63.72	63.73
CL16.3	6 12	-69.7740	-0.3030	1.73	63.83	63.86
	6 12 ^a	-69.7758	-0.3029	1.73	63.83	63.83
	6 13	-69.7740	-0.3030	1.73	63.83	64.05
	6 13 ^a	-69.7758	-0.3029	1.73	63.79	63.79
Band calculation ^b	6 12	-69.7758	-0.3028	1.73	63.79	63.79

^aIncreased by a factor of 8 with shrinking factors $s_1 = s_2 = s_3 = 2$

^bPrimitive unit cell with shrinking factors $s_1 = s_2 = s_3 = 6$

cyclic cluster. This property of cyclic clusters is important as, for example, the more compact cluster C4.3 gives results closer to the band calculation limit than the larger but less compact cluster C8.2. In order to construct more compact clusters, the anisotropy of the rutile structure ($a \approx 1.5c$) has to be taken into account.

Table 6.5 shows the effect of integral thresholds on the calculated properties of cyclic clusters.

For the cyclic cluster C12.1, the calculated properties are close to those for C16.3, but the difference $N_e^S - N_e^C$ is much larger, 3.2, *that is*, the DM is nonidempotent. It is well known that small changes of only the most severe integral threshold do not essentially affect the results [314]. Therefore, its decrease may restore the DM idempotency, while the calculated properties are only slightly changed. It is demonstrated in Table 6.5 that by using $t_5 = 9$ instead of 12, the difference $N_e^S - N_e^C$ decreases drastically to 0.10 for the same cluster, C12.1. For C16.1, the influence of t_5 is also small. For a cyclic cluster that has been chosen properly, an increase of the cyclicity region has to give only small changes in the calculated results.

In CCM calculations of defective crystals, such an increase of the cyclicity region allows investigation of the convergence of the results with cluster size. As is seen from Table 6.4, the $\mathbf{k}$ -sets accuracy J is important to reproduce the total energy. The cyclic-cluster increase without change of J (clusters C4.1 and C8.2 with $J = 1$, clusters C8.1, C16.1, and C16.4 with $J = 4$) gives only small changes in total energy. The cyclic clusters C12.1 and C16.3 generate highly accurate SP-sets ($J = 9$ and $J = 15$, respectively), and therefore the corresponding total energies are close to that of the infinite crystal. The same applies to the one-electron energy at the top of the valence band.

Table 6.6 MSINDO CCM results for bulk rutile; total energy per unit cell E_{tot} (a.u.), binding energy per unit E_{B} (kJ/mol), HOMO energy ϵ_{top} (a.u.), atomic Löwdin charge on Ti q_{Ti}

Cluster	E_{tot}	E_{B}	ϵ_{top}	q_{Ti}
CL8.1	-70.2164	1,880	-0.2947	1.74
CL12.1	-70.0959	1,722	-0.2910	1.77
CL24.2	-70.3774	2,092	-0.2898	1.77
CL32.2	-70.3428	2,046	-0.2885	1.77

The idempotency of the DM in MSINDO cyclic-cluster calculations is guaranteed for all cases as the periodic boundary conditions were introduced into the molecular code. This was tested in [95] for the cyclic cluster C12.1 in two ways:

1. By calculating the difference $C_M^{(1)} - C_M^{(2)}$ obtained with relation (6.76)
2. By directly calculating $P^2 - 2P$ and summing the absolute values of the differences over all matrix elements, $\Delta = \sum_{\mu\nu} |P_{\mu\nu}^2 - 2P_{\mu\nu}|$

By both ways of calculation, it was clearly demonstrated that the MSINDO CCM density matrix is exactly idempotent. The differences of covalencies $C_M^{(1)}$ and $C_M^{(2)}$ as well as Δ are in the same order of magnitude as the SCF threshold, 10^{-8} . At the same time, the symmetry of the crystalline system was correctly reproduced as checked by counting the degenerate one-electron levels in the oxygen 2s valence-band region and comparison with the results of a symmetry analysis. The symmetry of the cyclic cluster is different from the molecular cluster due to the presence of additional translation symmetry elements. Therefore, highly degenerate (8,4 degenerated) one-electron levels appear that are not present in any molecular model of rutile.

The calculated binding energies per unit cell E_{B} , HOMO orbital energies ϵ_{top} , and atomic Löwdin charges q for a number of cyclic clusters embedded in an infinite Madelung field, C8.1, C12.1, C24.2, and C32.2, are given in Table 6.6 [311].

The geometry of the four clusters has been optimized in terms of the three structural parameters c , $R_{\text{TiO}_{(5)}}$, and $R_{\text{TiO}_{(3)}}$. At low temperatures, the experimental references are $c = 2.954 \text{ \AA}$, $R_{\text{TiO}_{(5)}} = 1.946 \text{ \AA}$, and $R_{\text{TiO}_{(3)}} = 1.976 \text{ \AA}$. For the largest cyclic cluster, C32.3, the corresponding MSINDO values are $2.96 \text{ \AA}$, $1.90 \text{ \AA}$, and $1.91 \text{ \AA}$, which are in reasonable agreement with experiment. From Table 6.6, it can be seen that the convergence of E_{tot} is much slower than for the periodic HF calculations, see Table 6.3. On the other hand, ϵ_{top} and q_{Ti} show a similar convergence behavior. The MSINDO binding energies per TiO_2 unit E_{B} vary between 1,722 and 2,096 kJ/mol and are close to the experimental value of 1,900 kJ/mol. The calculated HOMO orbital energies for MSINDO (Table 6.6) and HF and HF (Table 6.5) are similar. The MSINDO ϵ_{top} is only 0.6 eV less negative than the HF result.

The density matrix idempotency relations described here may be easily extended to the unrestricted Hartree–Fock (UHF) method when the orbitals for α and β spins are treated independently.

As it is seen from the HF calculations of bulk rutile structure, the CCM technique produces a good representation of the perfect crystal, which is essential for point-defect studies.

Chapter 7

Kohn–Sham LCAO Method for Periodic Systems

The progress in the electron-correlation study of solids is connected mainly with the density-functional theory (DFT), determining directly the various physical properties of a system without any knowledge of the many-electron wavefunction. Unfortunately, for the density-functional-based methods, there is no procedure for a systematic improvement of the calculated results when a higher accuracy is desired. Modeling the exchange and correlation interactions becomes difficult within DFT as the exact functionals for the exchange and correlation are not known except for the homogeneous (uniform) electron gas. We discuss approximations that permit the calculation of real periodic systems: LDA, GGA, and hybrid Hartree–Fock/Kohn–Sham (orbital dependent) exchange–correlation functionals. In solid-state calculations, however, the use of hybrid functionals is not common because of the high computational cost that an exact exchange involves (both in LCAO and plane-wave calculations). Meanwhile, realistic bandgaps can be obtained only when hybrid functionals are used. A recent alternative to conventional hybrid functionals is a screened exchange hybrid functional developed by Heyd, Scuseria, and Ernzerhof (HSE). This functional uses a screened Coulomb potential for the exact exchange interaction, drastically reducing its computational cost and providing results of similar quality to the traditional hybrid functionals. It was demonstrated that the screened HF exchange (neglect of the computationally demanding long-range part of the HF exchange) exhibits all the physically relevant properties of the full HF exchange. The recent studies of a set of 40 binary semiconductors confirmed the efficiency of the HF/DFT approach for solids and also the use of the HSE hybrid functional. The problem of molecular exchange–correlation functional transferability to crystals is discussed. The density-functional SIC-DFT and DFT+U approaches are efficient for the strongly correlated systems—crystals containing $3d$ states in transition-metal atoms and $4f$ states in rare-earth atoms.

7.1 Foundations of the Density-Functional Theory

7.1.1 The Basic Formulation of the Density-Functional Theory

Density-functional theory has its conceptual roots in the Thomas–Fermi model of a uniform electron gas [315, 316] and the Slater local exchange approximation [317]. A formalistic proof for the correctness of the Thomas–Fermi model was provided by Hohenberg–Kohn theorems [318]. DFT has been very popular for calculations in solid-state physics since the 1970s. In many cases, DFT with the local-density approximation and plane waves as basis functions gives quite satisfactory results, for solid-state calculations, in comparison to experimental data at relatively low computational costs when compared to other ways of solving the quantum-mechanical many-body problem.

It took a long time for quantum chemists to recognize the possible contribution of DFT. A possible explanation of this is that the molecule is a very different object to the solid as the electron density in a molecule is very far from uniform [319]. DFT was not considered accurate enough for calculations in molecular quantum chemistry until the 1990s, when the approximations used in the theory were greatly refined to better model the exchange and correlation interactions. DFT is now a leading method for electronic-structure calculations in both fields. In quantum chemistry of solids, DFT LCAO calculations now have become popular especially with the use of so-called hybrid functionals including both HF and DFT exchange.

Traditional quantum chemistry starts from the electronic Schrödinger equation (SE) and attempts to solve it using increasingly more accurate approaches (Hartree–Fock and different post-Hartree–Fock methods, see Chaps. 4 and 5). These approaches are based on the complicated many-electron wavefunction (and are therefore called wavefunction-based methods), and in these *ab initio* methods, no semiempirical parameters arise. Such an approach can be summarized by the following sequence [320]: $V(\mathbf{r}) \xrightarrow{SE} \Psi(\mathbf{r}_1, \mathbf{r}_2, \dots, \mathbf{r}_N) \xrightarrow{\langle \Psi | \dots | \Psi \rangle} \text{observables}$, *that is*, one specifies the system by choosing potential $V(\mathbf{r})$, plugs it into the Schrödinger’s equation, solves that equation for the wavefunction $\Psi(\mathbf{r}_1, \mathbf{r}_2, \dots, \mathbf{r}_N)$, and then calculates observables by taking the expectation values of operators with this wavefunction. One among the observables that are calculated in this way is the one-electron density:

$$\rho(\mathbf{r}) = N \int d^3\mathbf{r}_2 \int d^3\mathbf{r}_3 \dots \int d^3\mathbf{r}_N \Psi^*(\mathbf{r}, \mathbf{r}_2, \dots, \mathbf{r}_N) \Psi(\mathbf{r}, \mathbf{r}_2, \dots, \mathbf{r}_N) \quad (7.1)$$

In DFT, the density (7.1) becomes the key variable: DFT can be summarized by the sequence

$$\rho(\mathbf{r}) \rightarrow \Psi(\mathbf{r}_1, \mathbf{r}_2, \dots, \mathbf{r}_N) \rightarrow V(\mathbf{r})$$

that is, knowledge of $\rho(\mathbf{r})$ implies knowledge of the wavefunction and the potential and hence of all other observables. This also represents the fact that ultimately

the electron density and not a wavefunction is the observable. Although this sequence describes the conceptual structure of DFT, it does not really represent what is done in actual applications of it and does not make explicit the use of many-body wavefunctions. Some chemists until now consider DFT as a containing “semiempirism”(not *ab initio*) method but recognize that the small number of semiempirical parameters are used in DFT and these parameters are “universal to the whole chemistry” [319].

Two core elements of DFT are the Hohenberg–Kohn (HK) theorems [318, 321] and the Kohn–Sham equations [322]. The former is mainly conceptual, but via the second, the most common implementations of DFT have been done.

Whereas the many-electron wavefunction is dependent on $3N$ variables, three spatial variables for each of the N electrons, the density is only a function of three variables and is a simpler quantity to deal with both conceptually and practically.

The literature on DFT and its applications is large. Some representative examples are the following: books [323–327], separate chapters of monographs [8, 10, 97], and review articles [320, 328–330].

We give here basic formulation of DFT and the Kohn–Sham method in the spirit of a “bird’s-eye view of DFT” [320], referring the reader for the mathematical details to the original papers. The original Hohenberg–Kohn (HK) theorems [318] held only for the ground state in the absence of a magnetic field, although they have since been generalized. The theorems can be extended to the time-dependent domain DFT (TDDFT), which can also be used to determine excited states [331]. Nevertheless, the inability of the DFT method to describe for molecular systems the spin and space degenerate states [332], as the diagonal element of the full density matrix is invariant with respect to all operations of the symmetry group, was proven.

The first HK theorem demonstrates the existence of a one-to-one mapping between the ground-state electron density (7.1) and the ground-state wavefunction of a many-particle system. The first Hohenberg–Kohn theorem is only an existence theorem, stating that the mapping exists but does not provide any such exact mapping. It is in these mappings that approximations are made. Let us rewrite (4.7) for the many-electron function of the system in the form

$$H\Psi = [T + V + U]\Psi = \left[-\frac{1}{2} \sum_{i=1}^N \Delta_i + \sum_{i=1}^N V(\mathbf{r}_i) + \sum_{i<j} U(\mathbf{r}_i, \mathbf{r}_j) \right] \Psi = E\Psi \quad (7.2)$$

where H is the electronic Hamiltonian, N is the number of electrons, and U is the electron–electron interaction. The operators T and U are so-called universal operators as they are the same for any system, while V is system dependent (nonuniversal). The potential V is called the external potential. This may be not only that of nuclei but also for cases when the system is exposed to an external electrostatic or magnetic field. We can write it as a sum of one-electron potentials $\sum_{i=1}^N V(\mathbf{r}_i)$, but we do not know this potential in advance. The actual difference

between a single-electron problem and the much more complicated many-electron problem just arises from the electron–electron interaction term U .

Hohenberg and Kohn proved [318] that the relation (7.1) can be reversed, *that is*, to a given ground-state density $\rho(\mathbf{r})$, it is in principle possible to calculate the corresponding ground-state wavefunction $\Psi_0(\mathbf{r}_1, \mathbf{r}_2, \dots, \mathbf{r}_N)$. This means that for a given ground-state density for some system, we cannot have two different external potentials V . This means that the electron density $\rho(\mathbf{r})$ defines all terms in the Hamiltonian (7.2) and therefore we can, in principle, determine the complete N -electron wavefunction for the ground state by only knowing the electron density. The HK theorem shows only that it is possible to calculate any ground-state property when the electron density is known but does not give the means to do it. Since the wavefunction is determined by the density, we can write it as $\Psi_0 = \Psi_0[\rho]$, which indicates that Ψ_0 is a function of its N spatial variables, but a *functional* of $\rho(\mathbf{r})$. More generally, a functional $F[n]$ can be defined as a rule for going from a function to a number, just as a function $y = f(x)$ is a rule (f) for going from a number (x) to a number (y). A simple example of a functional is the total number of electrons in a system N :

$$N = \int d^3\mathbf{r} \rho(\mathbf{r}) = N[\rho(\mathbf{r})] \quad (7.3)$$

which is a rule for obtaining the number N , given the function $\rho(\mathbf{r})$. Note that the name given to the argument of ρ is completely irrelevant, since the functional depends on the *function* itself, not on its variable. Hence, we do not need to distinguish $F[\rho(\mathbf{r})]$ from, for example, $F[\rho(\mathbf{r}')]$. Another important case is that in which the functional depends on a parameter, such as in

$$V_H[\rho(\mathbf{r})] = \int d^3\mathbf{r}' \frac{\rho(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} \quad (7.4)$$

that is a rule that for any value of the parameter $\mathbf{r}$ associates a value $V_H[\rho(\mathbf{r})]$ with the function $\rho(\mathbf{r}')$. This term is the so-called Hartree potential, introduced in (4.16) and is a potential of the Coulomb field created by all electrons of the system, with the electron in question included.

DFT explicitly recognizes that nonrelativistic Coulomb systems differ only by their external potential $V(\mathbf{r})$ and supplies a prescription for dealing with the universal operators T and U once and for all. This is done by promoting the electron density $\rho(\mathbf{r})$ from just one of many observables to the status of the key variable, on which the calculation of all other observables can be based. In other words, Ψ_0 is a unique functional of ρ , *that is*, $\Psi_0[\rho]$, and consequently, all other ground-state observables O are also functionals of ρ :

$$\langle O \rangle[\rho] = \langle \Psi_0[\rho] | \hat{O} | \Psi_0[\rho] \rangle \quad (7.5)$$

From this, it follows, in particular, that also the ground-state energy is a functional of ρ :

$$E_0 = E[\rho] = \langle \Psi_0[\rho] | T + V + U | \Psi_0[\rho] \rangle \quad (7.6)$$

where the contribution of the external potential can be written explicitly in terms of the density

$$V[\rho] = \int V(\mathbf{r})\rho(\mathbf{r})d^3\mathbf{r} \quad (7.7)$$

The functionals $T[\rho]$ and $U[\rho]$ are called universal functionals, while $V[\rho]$ is obviously nonuniversal, as it depends on the system under study. Having specified a system, *that is*, V is known, one then has to minimize the functional

$$E[\rho] = T[\rho] + U[\rho] + \int V(\mathbf{r})\rho(\mathbf{r})d^3\mathbf{r} \quad (7.8)$$

with respect to $\rho(\mathbf{r})$, assuming one has got reliable expressions for $T[\rho]$ and $U[\rho]$. The second HK theorem proves that the ground-state density minimizes the total electronic energy of the system. It states that once the functional that relates the electron density with the total electronic energy is known, one may calculate it approximately by inserting approximate densities ρ' . Furthermore, just as for the variational method for wavefunctions, one may improve any actual calculation by minimizing the energy functional $E[\rho']$. A successful minimization of the energy functional will yield the ground-state density ρ_0 and thus all other ground-state observables. A practical scheme for calculating ground-state properties from electron density was provided by the approach of Kohn and Sham [322] considered in the next section.

7.1.2 The Kohn–Sham Single-Particle Equations

Within the framework of Kohn–Sham (KS) DFT, the intractable many-body problem of interacting electrons in a static external potential is reduced to a tractable problem of noninteracting electrons moving in an effective potential. The functional in (7.8) is written as a fictitious density functional of a noninteracting system:

$$E_{\text{eff}}[\rho] = \langle \Psi_{\text{eff}}[\rho] | T_{\text{eff}} + V_{\text{eff}} | \Psi_{\text{eff}}[\rho] \rangle \quad (7.9)$$

where T_{eff} denotes the noninteracting electrons' kinetic energy and V_{eff} is an external effective potential in which the electrons are moving. It is assumed that the fictitious (model) system has the same energy as the real system. Obviously, $\rho_{\text{eff}}(\mathbf{r}) = \rho(\mathbf{r})$ if V_{eff} is chosen to be

$$V_{\text{eff}} = V + U + (T - T_{\text{eff}}) \quad (7.10)$$

Thus, one can solve the so-called Kohn–Sham equations of this auxiliary noninteracting system with the effective Hamiltonian

$$H_{\text{eff}} = \sum_{i=1}^N \left[-\frac{1}{2}\Delta_i + V_{\text{eff}}(\mathbf{r}_i) \right] = \sum_{i=1}^N h_{\text{eff}}(\mathbf{r}_i) \quad (7.11)$$

that yields the orbitals $\varphi_i(\mathbf{r})$ that reproduce the density $\rho(\mathbf{r})$ of the original many-electron system $\rho(\mathbf{r}) = \rho_{\text{eff}}(\mathbf{r}) = \sum_{i=1}^N |\varphi_i(\mathbf{r})|^2$. The effective single-electron potential $V_{\text{eff}}(\mathbf{r})$ can be written as

$$V_{\text{eff}}(\mathbf{r}) = V + \int \frac{\rho_{\text{eff}}(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} d^3\mathbf{r}' + V_{\text{XC}}[\rho_{\text{eff}}(\mathbf{r})] \quad (7.12)$$

where the second term denotes the so-called Hartree term describing the electron–electron Coulomb repulsion, while the last term V_{XC} is called the exchange–correlation potential and includes all the many-electron interactions. Since the Hartree term and V_{XC} depend on $\rho(\mathbf{r})$ that depends on the φ_i , which in turn depend on V_{eff} , the problem of solving the Kohn–Sham equation has to be done in a self-consistent (i.e., iterative) way. Usually, one starts with an initial guess for $\rho(\mathbf{r})$, then calculates the corresponding V_{eff} and solves the Kohn–Sham equations for the φ_i . From these, one calculates a new density and starts again. This procedure is then repeated until convergence is reached.

There are only single-particle operators in (7.11). Therefore, the solution to the Schrödinger equation for a model system of noninteracting electrons can be written exactly as a single Slater determinant $\Psi = |\varphi_1, \varphi_2, \dots, \varphi_N|$, where the single-particle orbitals φ_i are determined as solutions of the single-particle equation:

$$h_{\text{eff}}\varphi_i = \varepsilon_i\varphi_i \quad (7.13)$$

Furthermore, $\rho(\mathbf{r}) = \sum_{i=1}^N |\varphi_i(\mathbf{r})|^2$, where the summation runs over the N orbitals with the lowest eigenvalues ε_i .

The main problem is that we do not know the exact form of the effective potential V_{eff} , *that is*, the so-called exchange–correlation energy and potential. There exist approximations to these (see Sects. 7.1.3 and 7.1.4) that are good approximations in very many cases. On the other hand, by introducing an approximation in the Schrödinger equation for the model noninteracting particles, we do not know whether improved calculations (*e.g.*, using larger basis sets) also lead to improved results (compared with, *e.g.*, experiment or other calculations). The success of the Kohn–Sham approach is based on the assumption that it is possible to construct the model system of noninteracting particles moving in an effective external potential. Thus, it is indirectly assumed that for any ground-state density, there exists an effective potential (the corresponding density matrix is called V representative). There exist (specifically constructed) examples where this is not the case, but in most practical applications, this represents no problem [8].

HK theorems and KS equations can be extended to the spin-polarized systems where the electron-density components $\rho_\alpha(\mathbf{r}), \rho_\beta(\mathbf{r})$ for spin-up and spin-down orbitals differ, *that is*, the spin-density $\rho^s(\mathbf{r}) = \rho_\alpha(\mathbf{r}) - \rho_\beta(\mathbf{r})$ is nonzero.

The result is that the total energy and any other ground-state properties become a functional not only of $\rho(\mathbf{r})$ but also of spin-density $\rho^s(\mathbf{r})$, *that is*, $E_{\text{eff}} = E[\rho(\mathbf{r}), \rho^s(\mathbf{r})]$. Spin-density-functional theory (SDFT) is a widely implemented and applied formalism of DFT.

Alternative DFT formulations that use other variables in addition to (or instead of) the spin densities are also useful [333].

The single-particle orbitals and complete N -electron wavefunctions in KS DFT belong to irreducible representations of the group for the symmetry operations of the system of interest (point-symmetry group for molecules and space-symmetry group for crystals). This means that we can consider each irreducible representation separately. For each of these, the variational principle will apply (since any state of a given irreducible representation will only contain contributions from exactly that irreducible representation). We can use this in generalizing the HK theorems that then apply for the energetically lowest state of each irreducible representation. This means that if we have the representations D^α , D^β for a given system symmetry group, then we can apply DFT in studying the energetically lowest state for the D^α representation, that for the D^β representation and so on, but not energetically higher ones of any of the representations.

Since 1990, there has been an enormous amount of comparison for molecules between DFT KS and HF (MO) theory. Such a comparison is easily extended to crystals when we consider CO instead of MO. The discussion of advantages and disadvantages of DFT compared to MO theory can be found, for example, in [97], and is briefly reproduced here. The most fundamental difference between DFT and MO theory is the following: DFT optimizes an electron density, while MO theory optimizes a wavefunction. So, to determine a particular molecular property using DFT, we need to know how that property depends on the density, while to determine the same property using a wavefunction, we need to know the correct quantum-mechanical operator. As a simple example, consider the total energy of interelectronic repulsion. Even if we had the exact density for some system, we do not know the exact exchange-correlation energy functional, and thus, we cannot compute the exact interelectronic repulsion. However, with the exact wavefunction, it is a simple matter of evaluating the expectation value for the interelectronic repulsion operator to determine this energy. Thus, it is easy to become confused about whether there exists a KS “wavefunction”. Formally, the KS orbitals are pure mathematical constructs useful only in construction of the density. In practice, however, the shapes of KS orbitals tend to be remarkably similar to canonical HF MOs, and they can be quite useful in qualitative analysis of chemical properties. If we think of the procedure by which they are generated, there are indeed a number of reasons to prefer KS orbitals to HF orbitals. For instance, all KS orbitals, occupied and virtual, are subject to the same external potential. HF orbitals, on the other hand, experience varying potentials, and, in particular, HF virtual orbitals experience the potential that would be felt by an extra electron being added to the molecule. As a result, HF virtual orbitals tend to be too high in energy and anomalously diffuse compared to KS virtual orbitals. This fact is especially important for crystalline solids and explains why HF bandgaps are overestimated compared to those in DFT and experiment. Unfortunately, for some choices of exchange-correlation potential DFT, bandgaps are too small in comparison with the experimental data. In *exact* DFT, it can also be shown that the eigenvalue of the highest KS MO is the exact first ionization potential, *that is*, there is a direct analogy to Koopmans’ theorem for this

orbital—in practice, however, *approximate* functionals are quite poor at predicting IPs in this fashion without applying some sort of correction scheme, *for example*, an empirical linear scaling of the eigenvalues.

The Slater determinant formed from the KS orbitals is the exact wavefunction for the fictitious *noninteracting* system having the same density as the real system. This KS Slater determinant has certain interesting properties by comparison to its HF analogs. It is an empirical fact that DFT is generally much more robust in dealing with open-shell systems where UHF methods show high spin contamination, *that is*, incorporates some higher spin states (doublets are contaminated by quartets and sextets, while triplets are contaminated by pentets and heptets). The degree of spin contamination can be estimated by inspection of $\langle S^2 \rangle$, which should be 0.0 for a singlet, 0.75 for a doublet, 2.00 for a triplet, etc. Note, incidentally, that the expectation values of S^2 are sensitive to the amount of HF exchange in the functional. A “pure” DFT functional nearly always shows very small spin contamination, and each added percent of HF exchange tends to result in a corresponding percentage of the spin contamination exhibited by the HF wavefunction. This behavior can make the hybrid HF–DFT functionals useful for open-shell systems (see Sect. 4.1.2).

The formal scaling behavior of DFT is, in principle, no worse than N^3 , where N is the number of basis functions used to represent the KS orbitals. This is better than HF by a factor of N and very substantially better than other methods that include electron correlation (see Chap. 5).

The most common methods for solving KS equations proceed by expanding the Kohn–Sham orbitals in a basis set. DFT has a clear advantage over HF in its ability to use basis functions that are not necessarily contracted Gaussians. The motivation for using contract GTOs is that arbitrary four-center two-electron integrals can be solved analytically. In the electronic-structure programs where DFT was added as a new feature to an existing HF code, the representation of the density in the classical electron-repulsion operator is carried out using the KS orbital basis functions. Thus, the net effect is to create a four-index integral, and these codes inevitably continue to use contracted GTOs as basis functions. In particular, such a scheme is used in the CRYSTAL code [21]. However, if the density is represented using an auxiliary basis set, or even represented numerically, other options are available for the KS orbital basis set, including Slater-type functions. The SIESTA density-functional code (<http://www.uam.es/departamentos/ciencias/fismateriac/siesta/>) for crystalline solids uses numerical AO basis instead of GTO. Slater-type orbitals (STO) enjoy the advantage that fewer of them are required (since they have the correct cusp behavior at the nuclei) and certain advantages associated with symmetry can more readily be taken, so they speed up calculations considerably. The Amsterdam density-functional code and its BAND version for solids (<http://www.scm.com/Doc/Doc2006.01>) make use of STO basis functions covering atomic numbers 1–118. Some information about the three-mentioned computer LCAO codes for solids is given in Appendix C.

Another interesting possibility is the use of plane waves as basis sets in periodic infinite systems (crystalline solids) represented using periodic boundary conditions. While it takes an enormous number of plane waves to properly represent the

decidedly aperiodic densities that are possible within the unit cells of interesting chemical systems, the necessary integrals are particularly simple to solve, and thus, this approach has found wide use in solid-state physics.

Meanwhile, plane-wave basis use excludes the possibility of calculations with hybrid DFT–HF functionals.

7.1.3 *Exchange and Correlation Functionals in the Local-Density Approximation*

The effective potential (7.10) includes the external potential and the effects of the Coulomb interactions between the electrons, *for example*, the exchange and correlation interactions. In principle, it also includes the difference in kinetic energy between the fictitious noninteracting system and the real system. In practice, however, this difference is ignored in many modern functionals as the empirical parameters appear, which necessarily introduce some kinetic-energy correction if they are based on experiment [97].

Modeling the exchange and correlation interactions becomes difficult within KS DFT as the exact functionals for exchange and correlation are not known except for the homogeneous (uniform) electron gas. However, approximations exist that permit the calculation of real systems.

The simplest approximation is the local-density approximation (LDA), based upon the exact exchange energy for a uniform electron gas, which can be obtained from the Thomas–Fermi (TF) model, and from fits to the correlation energy for a uniform electron gas.

In the TF model, it is suggested that the number of electrons is so large that the system could be treated using quantum-statistical arguments. The approximation in the TF model concerns the kinetic energy. For the homogeneous interaction free-electron gas, the density is constant and the average kinetic energy per particle is $\varepsilon_t^{\text{hom}} = Cn^{5/3}$. The kinetic energy per unit volume in this model is $n\varepsilon_t^{\text{hom}}$. If the electron density varies sufficiently slowly in space, $T^{\text{LDA}} = \int d^3r \varepsilon_t^{\text{hom}}(\rho(\mathbf{r}))$ may serve as a workable approximation for the kinetic-energy functional.

If this is combined with the expression for the nuclei–electron attractive potential and the electron–electron Hartree repulsive potential, we have the TF expression for the energy of a homogeneous gas of electrons in a given external potential:

$$E_{\text{TF}}[\rho(\mathbf{r})] = C_F \int \rho^{5/3}(\mathbf{r}) d^3\mathbf{r} - \sum_j \frac{Z_j}{|\mathbf{r} - \mathbf{R}_j|} \rho(\mathbf{r}) + \frac{1}{2} \int \int \frac{\rho(\mathbf{r})\rho(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} d^3\mathbf{r} d^3\mathbf{r}' \quad (7.14)$$

The importance of this equation is not so much how well it is able to really describe the energy even of an atom but that the energy is given completely in terms of the electron density $\rho(\mathbf{r})$.

This is an example of a density-functional for energy allowing us to map a density $\rho(\mathbf{r})$ onto an energy E without any additional information required. Furthermore, the TF model employs the variational principle assuming that the ground state of the system is connected to the electron density for which the energy (7.14) is minimized under the constraint of $N = \int d^3\mathbf{r} \rho(\mathbf{r})$.

Before the Kohn–Sham theorems were proved, it was not known either whether expressing the energy as a density functional is physically justified or whether employing the variational principle on the density is really allowed [327].

Slater’s approximation of HF exchange [334] is another example of exploiting the electron density as the central quantity. In this case, the nonlocal HF exchange energy is approximated by $\alpha \cdot C \cdot \int \rho(\mathbf{r})^{4/3} d\mathbf{r}$.

This approximate expression depends only on the local values of the electron density $\rho(\mathbf{r})$ representing a density functional for the exchange energy (in the TF model, exchange and correlation effects are completely neglected). This formula was originally derived as an approximation to the HF exchange, without any reference to the density-functional theory, but it is conceptually connected with this theory. The 4/3 power law for dependence of the exchange interaction on the electron density was also obtained from a completely different approach using the concept of the uniform electron gas [335]. Combined with the TF energy, this approximation is known as the Thomas–Fermi–Dirac model having conceptual importance for DFT methods. In particular, it seems natural that the exchange–correlation energy E_{XC} is approximated by sum of the exchange E_X and correlation E_C energies.

In LDA for the exchange energy calculation, the Dirac–Slater exchange energy is used:

$$E_X[\rho] = C_X \int \rho^{4/3}(\mathbf{r}) d^3\mathbf{r} \quad (7.15)$$

or the more complicated suggested by Barth and Hedin [336].

For the correlation energy functional $E_C[\rho(\mathbf{r})]$, the situation is more complicated since even for a homogeneous electron gas, it is not known exactly. Early approximate expressions for correlation in homogeneous systems were based on applying the perturbation theory and were suggested by Barth and Hedin [336] and Gunnarsson and Lundqvist [337]. With the advent of highly precise calculations of correlation energy for the electron liquid by Ceperley and Alder (CA) [338], the approximations for the correlation energy in a homogeneous system are made by parametrization of CA data for a free-electron gas. There are known parametrizations of Vosko–Wilk–Nisair [339], Perdew–Zunger [340], and Perdew–Wang [341]. The three latter parametrizations of the LDA are implemented in most standard DFT program packages (both for molecules and solids) and in many cases give almost identical results. On the other hand, the earlier parametrizations of the LDA, based on perturbation theory, can deviate substantially and are better avoided.

The functional dependence of E_{XC} on the electron density is expressed as an interaction between the electron density and “an energy density” ε_{XC} that is dependent on the electron density

$$E_{\text{XC}}[\rho(\mathbf{r})] = \int \rho(\mathbf{r}) \varepsilon_{\text{XC}}[\rho(\mathbf{r})] d^3\mathbf{r} \quad (7.16)$$

The energy density ε_{XC} is treated as a sum of individual exchange and correlation contributions. Two different kinds of densities are involved [97]: the electron density is a per unit volume density, while the energy density is a per particle density. The LDA for E_{XC} formally consists in

$$E_{\text{XC}}^{\text{LDA}}[\rho(\mathbf{r})] = \int d^3\mathbf{r} [\varepsilon_{\text{X}}^{\text{hom}}[\rho(\mathbf{r})] + \varepsilon_{\text{C}}^{\text{hom}}[\rho(\mathbf{r})]] = \int d^3\mathbf{r} \varepsilon_{\text{XC}}^{\text{hom}}[\rho(\mathbf{r})] \quad (7.17)$$

The energy densities $\varepsilon_{\text{X}}^{\text{hom}}$, $\varepsilon_{\text{C}}^{\text{hom}}$ refer to a homogeneous system, *that is*, the exchange-correlation energy is simply an integral over all space with the exchange-correlation energy density at each point assumed to be the same as in a homogeneous electron gas with that density. Nevertheless, LDA has proved amazingly successful, even when applied to systems that are quite different from the electron liquid that forms the reference system for the LDA.

In the local spin-density approximation (LSDA), the exchange-correlation energy can be written in terms of either of two spin densities $\rho^{\alpha}(\mathbf{r})$ and $\rho^{\beta}(\mathbf{r})$:

$$\begin{aligned} E_{\text{XC}}^{\text{LSDA}}[\rho^{\alpha}(\mathbf{r}), \rho^{\beta}(\mathbf{r})] &= \int d^3\mathbf{r} \rho(\mathbf{r}) \varepsilon_{\text{XC}}^{\text{hom}}[\rho^{\alpha}(\mathbf{r}), \rho^{\beta}(\mathbf{r})] \\ &= \int d^3\mathbf{r} \rho(\mathbf{r}) [\varepsilon_{\text{X}}^{\text{hom}}[\rho^{\alpha}(\mathbf{r}), \rho^{\beta}(\mathbf{r})] \\ &\quad + \varepsilon_{\text{C}}^{\text{hom}}[\rho^{\alpha}(\mathbf{r}), \rho^{\beta}(\mathbf{r})]] \end{aligned} \quad (7.18)$$

or the total density $\rho(\mathbf{r})$ and the fractional spin polarization $\zeta(\mathbf{r}) = (\rho^{\alpha}(\mathbf{r}) - \rho^{\beta}(\mathbf{r}))/\rho(\mathbf{r})$.

For many decades, the LDA has been applied in, *for example*, calculations of band structures and total energies in solid-state physics. The LDA provides surprisingly good results for metallic solids with delocalized electrons, *that is*, those that most closely resemble the uniform electron gas (jellium). At the same time, there are well-known disadvantages of LDA for solids. LDA revealed systematic shortcomings in the description of systems with localized electrons and as a result, the underestimation of bond distances and overestimation of binding energies. LDA calculations as a rule give calculated bandgaps that are too small. In quantum chemistry of molecules, LDA is much less popular because the local formulation of the energy expression does not account for the electronic redistribution in bonds. For well-localized electrons, the nonexact cancelation of the self-energy part (self-interaction) of the Hartree term in the LDA exchange functional is important (in HF energy the self-energy part in the Hartree term is canceled by the corresponding part of the exchange term). LDA fails to provide results that are accurate enough to permit a quantitative discussion of the chemical bond in molecules (so-called chemical accuracy requires calculations with an error of not more than about

1 kcal/mol per particle). LDA exploits knowledge of the density at point $\rho(\mathbf{r})$. The real systems, such as molecules and solids, are inhomogeneous (the electrons are exposed to spatially varying electric fields produced by the nuclei) and interacting (the electrons interact via the Coulomb interaction). The way density-functional theory, in the local-density approximation, deals with this inhomogeneous many-body problem is by decomposing it into two simpler (but still highly nontrivial) problems: the solution of a spatially uniform many-body problem (the homogeneous electron liquid) yields the uniform exchange-correlation energy, and the solution of a spatially inhomogeneous noninteracting problem (the inhomogeneous electron gas) yields the particle density. Both steps are connected by the local-density approximation, which shows how the exchange-correlation energy of the uniform interacting system enters the equations for the inhomogeneous noninteracting system.

We note that both the local density approximation and the local-exchange approximation use only the diagonal part of the density matrix $\rho(\mathbf{r}, \mathbf{r}')$, that is, $\rho(\mathbf{r}) = \rho(\mathbf{r}, \mathbf{r})$. However, these approximations are different by their nature. In LDA the local density is used to include both the exchange and correlation of electrons; in the local exchange, approximation to HF exchange the electron correlation is not taken into account at all.

The particular way in which the inhomogeneous many-body problem is decomposed and the various possible improvements on the LDA are behind the success of DFT in practical calculations, in particular, materials. The most important improvement of LDA is connected with the attempt to introduce a spatially varying density and include information on the rate of this variation in the functional. The corresponding functionals, known as semilocal functionals [320], are considered in the next section.

7.1.4 *Beyond the Local-Density Approximation*

The first successful extensions for the LDA were developed in the early 1980s when it was suggested to supplement the density $\rho(\mathbf{r})$ at a particular point $\mathbf{r}$ with information about the gradient of the electron density at this point in order to account for the nonhomogeneity of the true electron density [327]. LDA was interpreted as the first term of a Taylor expansion of the uniform density, the form of the functional was termed the gradient expansion approximation (GEA). It was expected to obtain better approximations of the exchange-correlation functional by extending the series with the next lowest term. In practice, the inclusion of low-order gradient corrections almost never improves on the LDA and often even worsens it. The reason for this failure is that for GEA, the exchange-correlation hole has lost many of the properties that made the LDA whole physically meaningful [327]. Higher-order corrections, on the other hand, are exceedingly difficult to calculate, and little is known about them.

It was a major breakthrough when it was realized, in the early 1980s, that instead of power-series-like systematic gradient expansions, one could experiment with

more general functions of $\rho(\mathbf{r})$ and $\nabla\rho(\mathbf{r})$, which need not proceed order by order. Such functionals, of the general form

$$E_{\text{XC}}^{\text{GGA}}[\rho_\alpha, \rho_\beta] = \int d^3\mathbf{r} f(\rho_\alpha, \rho_\beta, \nabla\rho_\alpha, \nabla\rho_\beta) \quad (7.19)$$

have become known as generalized-gradient approximations (GGAs) [343]. GGA functionals are the workhorses of current density-functional theory. Different GGAs differ in the choice of the function $f(\rho, \nabla\rho)$. Note that this makes different GGAs much more different from each other than the different parametrizations of the LDA: essentially, there is only one correct expression for $\varepsilon_{\text{XC}}^{\text{hom}}(\rho)$, and the various parametrizations of the LDA are merely different ways of writing it [320]. On the other hand, depending on the method of construction employed for obtaining $f(\rho, \nabla\rho)$, one can obtain very different GGAs. In particular, GGAs used in molecular quantum chemistry typically proceed by fitting parameters to test sets of selected molecules. On the other hand, the GGAs used in physics tend to emphasize exact constraints on the density-functional for the exchange-correlation energy [345]. In this approach, the density-functional approximations are assigned to various rungs according to the number and kind of their local ingredients [345].

The lowest rung is the local spin-density approximation LSDA; the second rung is the generalized gradient approximation GGA (semilocal functionals). More accurate functionals of higher rungs can be called “beyond-GGA functionals” or nonlocal functionals. Third-rung meta-GGA (MGGA) functionals depend, in addition to the density and its derivatives, also on the kinetic-energy density [350]. Fourth-rung hybrid functionals mix a fraction of the Hartree–Fock exchange into the DFT exchange functional (see Sect. 4.2). MGGA and hybrid functionals can be called orbital functionals because they are represented not only in terms of the electron density but also contain parts represented in single-particle Kohn–Sham orbitals $\varphi_i(\mathbf{r})$. In MGGA functionals, kinetic-energy density $\tau(\mathbf{r}) = 1/2 \sum_i |\nabla\varphi_i(\mathbf{r})|^2$ is included. In hybrid functionals, the nonlocal HF exchange energy is also orbital functional. Still another type of orbital functional is the self-interaction correction (SIC) (see Sect. 7.2.5). Higher-rung density functionals are increasingly more complex.

The semiempirical functionals are fitted to selected data from experiment or from the *ab initio* calculations. The higher the rung of the functional, the larger is the number of parameters (functionals with as many as 21 fit parameters are popular in chemistry). Is DFT *ab initio* or semiempirical? As was suggested in [345], it can fall in between as a nonempirical theory when the functionals are constructed without empirical fitting.

The best nonempirical functional for a given rung is constructed to satisfy as many exact theoretical constraints as possible while providing satisfactory numerical predictions for real systems [345]. Once a rung has been selected, there remains little choice about which constraints to satisfy (but greater freedom in how to satisfy them), [345]. Accuracy is expected to increase up the ladder of rungs as additional local ingredients enable the satisfaction of additional constraints. A short

summary of exact constraints on $E_{\text{XC}}[\rho]$ can be found in [345]. In this paper, some useful recommendations for users of DFT are also given. Users should not randomly mix and match functionals, but should use exchange and correlation pieces designed to work together, with their designer-recommended local parts. They should not shop indiscriminately for the functional that “works best.” Users should always say which functional they used, with its proper name and literature reference, and why they chose it. Statements like “we used density-functional theory” or “we used the generalized gradient approximation” are almost useless to a reader or listener who wants to reproduce the results.

Nowadays, the most popular (and most reliable) GGA functionals are PBE (denoting the functional proposed in 1996 by Perdew, Burke, and Ernzerhof [352] in physics and BLYP (denoting the combination of Becke’s 1988 exchange functional [346] with the 1988 correlation functional of Lee et al. [347]) in chemistry. PWGGA denotes the GGA functional, suggested by Perdew and Wang [342, 343] and should be allowed to retire gradually. Many other GGA-type functionals are also available, and new ones continue to appear. The new meta-GGA (MGGA) functional TPSS (Tao–Perdew–Staroverov–Scuseria) [348] supersedes an older one, the PKZB (Perdew–Kurth–Zupan–Blaha) functional [351]. The known functionals are modified as has been done recently for the PBE functional to improve its accuracy for thermodynamic and electronic properties of molecules [349, 350].

We close this subsection with more detailed consideration of the PBE functional [351]. It has two nonempirical derivations based on exact properties of the XC hole [352] and energy [344]. In discussion of the PBE functional, we follow [353]. The exchange-correlation (XC) energy in the LSD approximation is given by

$$E_{\text{XC}}^{\text{LSD}}[\rho_\alpha, \rho_\beta] = \int d^3\mathbf{r} \rho(\mathbf{r}) [\varepsilon_{\text{X}}(\rho(\mathbf{r})) f(\zeta, \mathbf{r}) + \varepsilon_{\text{C}}(r_s(\mathbf{r}), \zeta(\mathbf{r}))] \quad (7.20)$$

where $\zeta = \frac{\rho_\alpha - \rho_\beta}{\rho_\alpha + \rho_\beta}$ is the relative spin polarization and $f(\zeta)$ is given by

$$f(\zeta) = \frac{1}{2} [(1 + \zeta)^{4/3} + (1 - \zeta)^{4/3}] \quad (7.21)$$

The exchange energy per electron $\varepsilon_{\text{X}}(\rho)$ of the unpolarized uniform electron gas of density $\rho(\mathbf{r})$ depends on $r_s = [\frac{3}{4\pi}\rho]^{1/3}$ as $\varepsilon_{\text{X}}(\rho) = -\frac{C}{r_s}$, and the correlation energy ε_{C} per electron in a spin-polarized uniform electron gas depends on r_s and ζ [342]. The PBE functional $E_{\text{XC}}^{\text{PBE}}$ is a sum of PBE exchange $E_{\text{X}}^{\text{PBE}}$ and PBE correlation $E_{\text{C}}^{\text{PBE}}$ functionals. The exchange PBE functional is written in the form

$$E_{\text{X}}^{\text{PBE}}(\rho) = \int d^3\mathbf{r} \rho \varepsilon_{\text{X}}(\rho) F_{\text{X}}(s) \quad (7.22)$$

with

$$F_{\text{X}}(s) = 1 + k - \frac{k}{1 + \mu s^2/k} \quad (7.23)$$

and $k = 0.804$, $\mu = 0.21951$. This functional is found from the exact spin-scaling relation:

$$E_X[\rho_\alpha, \rho_\beta] = \frac{1}{2}E_X[2\rho_\alpha] + \frac{1}{2}E_X[2\rho_\beta] \quad (7.24)$$

The PBE correlation energy functional is

$$E_C^{\text{PBE}}[\rho_\alpha, \rho_\beta] = \int d^3\mathbf{r} \rho[\varepsilon_C(r_s, \zeta) + H(r_s, \zeta, t)] \quad (7.25)$$

where the nonlocal part $H(r_s, \zeta, t)$ depends on the parameter t including the density gradient:

$$H = \gamma \Phi^3 \ln \left\{ 1 + \frac{\beta}{\gamma} t^2 \left[\frac{1 + At^2}{1 + At^2 + A^2 t^4} \right] \right\} \quad (7.26)$$

where $\beta = 0.066725$, $\gamma = 0.03191$, and

$$t = \left(\frac{\pi}{4} \right)^{1/2} \left(\frac{9\pi}{4} \right)^{1/6} \frac{s}{\Phi r_s^{1/2}} \quad (7.27)$$

$$s = \frac{|\nabla \rho|}{2(3\pi^2)^{1/3} \rho^{4/3}} = \frac{3}{2} \left(\frac{9}{4\pi} \right)^{1/3} |\nabla r_s| \quad (7.28)$$

$$\Phi(\zeta) = \frac{1}{2} [(1 + \zeta)^{2/3} + (1 - \zeta)^{2/3}] \quad (7.29)$$

$$A = \left(\frac{\beta}{\gamma} \right) \frac{1}{\exp[-\varepsilon_C(r_s, \zeta)/\gamma \Phi^3] - 1} \quad (7.30)$$

The PBE GGA correctly reduces to LSD for uniform electron densities, its correlation component recovers the slowly varying ($t \rightarrow 0$) and rapidly varying ($t \rightarrow \infty$) limits of numerical GGA. Under uniform scaling ($\rho(\mathbf{r}) \rightarrow \lambda^3 \rho(\lambda \mathbf{r})$), the PBE exchange energy scales like λ (as does the exact exchange functional), and the PBE correlation energy correctly scales to a constant as $\lambda \rightarrow \infty$. For small-amplitude density variations around a uniform density, LSD is a very good approximation. The PBE functional recovers this limit. The PBE functional satisfies the Lieb–Oxford bound [354]:

$$E_X^{\text{PBE}}[\rho_\alpha, \rho_\beta] \geq E_{XC}^{\text{PBE}}[\rho_\alpha, \rho_\beta] \geq 2.273 E_X^{\text{LDA}}[\rho] \quad (7.31)$$

A useful form to compare GGA functionals is to write

$$E_{XC}^{\text{GGA}}[\rho_\alpha, \rho_\beta] \approx \int d^3\mathbf{r} \rho \varepsilon_X(\rho) F_{XC}(r_s, \zeta, s) \quad (7.32)$$

where the enhancement factor $F_{XC}(r_s, \zeta, s)$ over local exchange depends upon the local radius r_s ($r_s \lesssim 1$ for core electrons and $r_s \gtrsim 1$ for valence electrons), spin polarization ζ , and inhomogeneity s . The s -dependence of F_{XC} is the nonlocality

of the GGA. We see that the nonempirical PBE functional best fulfills many of the physical and mathematical requirements of DFT. We will consider some applications of the PBE functional in LCAO calculations of crystals in Chaps. 9–11. At the same time, there are some failures of the PBE functional essential for extended systems. For example, the exact exchange-correlation hole in crystals may display a diffuse long-range tail that is not properly captured by GGA (such a diffuse hole arises in the calculation of the surface energy of a metal). Neither LSD nor GGA describes correctly the long-range tail of the van der Waals interaction. Corrections of these failures might be possible by using orbital-dependent hybrid functionals considered in the next section.

7.1.5 *The Pair Density: Orbital-Dependent Exchange-Correlation Functionals*

Density-functional theory, even with rather crude approximations such as LDA and GGA, is often better than Hartree–Fock: LDA is remarkably accurate, for instance, for geometries and frequencies, and GGA has also made bond energies quite reliable. Therefore, “the aura of mystery” appeared around DFT (see discussion of this by Baerends and Gritsenko [355]). The simple truth is not that LDA/GGA is particularly good, but that Hartree–Fock is rather poor in the two-electron chemical-bond description. This becomes clear when one considers the statistical two-electron distribution, which is usually cast in terms of the exchange-correlation hole: the decrease in probability to find other electrons in the neighborhood of a reference electron, compared to the (unconditional) one-electron probability distribution [327].

The concept of electron density (7.1), which provides an answer to the question “how likely is it to find one electron of arbitrary spin within a particular volume element, while all other electrons may be anywhere” can be extended to the probability of finding not one but a pair of two electrons with spins σ_1 and σ_2 simultaneously within two volume elements $d\mathbf{r}_1$ and $d\mathbf{r}_2$, while the remaining $N - 2$ electrons have arbitrary positions and spins. The quantity that contains this information is the pair-electron density $\rho_2(\mathbf{x}_1, \mathbf{x}_2)$ which is defined as

$$\rho_2(\mathbf{x}_1, \mathbf{x}_2) = N(N - 1) \int \dots \int \Psi(\mathbf{x}_1, \dots, \mathbf{x}_N)^2 d\mathbf{x}_3 \dots d\mathbf{x}_N \quad (7.33)$$

The pair-electron density actually contains all the information about electron correlation. The pair density is a nonnegative quantity, symmetric in the coordinates, and normalized to the total number of nondistinct electron pairs $N(N - 1)$. Obviously, if electrons would not interact, the probability of finding one electron at a particular point of coordinate-spin space would be completely independent of the position and spin of the second electron and it would be possible that both electrons are simultaneously found in the same volume element. In this case, pair density

would reduce to a simple product of the individual probabilities, *that is*,

$$\rho_2(\mathbf{x}_1, \mathbf{x}_2) = \frac{N-1}{N} \rho(\mathbf{x}_1) \rho(\mathbf{x}_2) \quad (7.34)$$

The $N(N-1)$ factor enters because the particles are identical. From the antisymmetry of the many-electron wavefunction $\Psi(\mathbf{x}_1, \dots, \mathbf{x}_N)$, it follows that $\rho_2(\mathbf{x}_1, \mathbf{x}_2) = -\rho_2(\mathbf{x}_2, \mathbf{x}_1)$, *that is*, the probability of finding two electrons with the same spin at the same point in space is zero.

This effect is known as exchange or Fermi correlation and is a direct consequence of the Pauli principle. The Fermi hole is in no way connected to the charge of electrons and applies equally to neutral fermions. This kind of correlation is included in the HF approach due to the antisymmetry of the Slater determinant [327]. The electrostatic repulsion of electrons (the $1/r_{12}$ term in the Hamiltonian) prevents the electrons from coming too close to each other and is known as Coulomb correlation. This effect is independent of the spin and is called simply electron correlation and is completely neglected in the HF method.

The conditional probability $\Omega(\mathbf{x}_1, \mathbf{x}_2) = \rho(\mathbf{x}_1, \mathbf{x}_2)/\rho(\mathbf{x}_1)$ defines the probability of finding any electron at position 2 in coordinate-spin space if there is one already known to be at position 1.

The exchange-correlation (xc) hole is defined as the difference between $\Omega(\mathbf{x}_1, \mathbf{x}_2)$ and the uncorrelated probability of finding an electron at $\mathbf{x}_2$:

$$h_{xc}(\mathbf{x}_1, \mathbf{x}_2) = \frac{\rho_2(\mathbf{x}_1, \mathbf{x}_2)}{\rho(\mathbf{x}_1)} - \rho(\mathbf{x}_2) = \rho(\mathbf{x}_2) f(\mathbf{x}_1, \mathbf{x}_2) \quad (7.35)$$

and contains exactly the charge of one electron $\int h_{xc}(\mathbf{x}_1, \mathbf{x}_2) d\mathbf{x}_2 = -1$, [327]. The function $f(\mathbf{x}_1, \mathbf{x}_2)$ is the correlation factor, being zero for the completely uncorrelated case.

The exchange-correlation hole describes the change in conditional probability caused by the correction for self-interaction, and exchange and Coulomb correlation, compared to the completely uncorrelated situation. It can formally be split into the Fermi hole, $h_x^{\sigma_1=\sigma_2}(\mathbf{r}_1, \mathbf{r}_2)$, and the Coulomb hole $h_c^{\sigma_1, \sigma_2}(\mathbf{r}_1, \mathbf{r}_2)$:

$$h_{xc}(\mathbf{x}_1, \mathbf{x}_2) = h_x^{\sigma_1=\sigma_2}(\mathbf{r}_1, \mathbf{r}_2) + h_c^{\sigma_1, \sigma_2}(\mathbf{r}_1, \mathbf{r}_2) \quad (7.36)$$

The exchange hole h_x applies only to electrons with the same spin, the correlation hole h_c has contributions for electrons of either spin and is the hole resulting from the $1/r_{12}$ electrostatic interaction. This separation is convenient, but only the total xc hole has a real physical meaning. In the HF method the Fermi hole is accounted for through the use of a single Slater determinant, whereas the Coulomb hole is neglected. Like the total hole, the Fermi hole contains exactly the charge of one electron $\int h_x(\mathbf{r}_1, \mathbf{r}_2) d\mathbf{r}_2 = -1$ and takes care of the self-interaction correction (SIC). The exchange hole h_x is negative everywhere $h_x(\mathbf{r}_1, \mathbf{r}_2) < 0$, and its actual

shape depends not only on the Fermi correlation factor but also on the density at $\mathbf{r}_2$. As a consequence, h_x is not spherically symmetric.

The Coulomb hole must be normalized to zero, and this result is independent of the positions of electrons with $\sigma' \neq \sigma$: $\int h_c(\mathbf{r}_1, \mathbf{r}_2) d\mathbf{r}_2 = 0$.

The essential error of Hartree–Fock arises from the fact that in the HF model the exchange–correlation hole in a two-electron bond is not centered around the reference electron, but is too delocalized, having considerable amplitude on both atoms involved in the bond. The LDA and GGA models incorporate, simply by using an electron-centered hole, an important part of the effect of the interelectron Coulomb repulsion.

To improve the LDA and GGA models, the orbital-dependent functionals are introduced. The introduction of orbital dependence, not only density and gradient dependence, into the functionals can be realized in different ways [320]. Hybrid HF–DFT functionals are the most popular beyond-GGA functionals. These functionals mix a fraction of HF exchange into the DFT exchange functional and use the DFT correlation part. But why is the exact HF exchange mixed with the approximate DFT exchange part? How can one find the weights of this mixing? Maybe it would be possible to use the exact HF exchange and rely on approximate functionals only for the part missing in the HF model, *that is*, the electron correlation: $E_{xc} = E_x^{\text{HF}} + E_c^{\text{KS}}$ (EXX—orbital-dependent exact exchange functional). The HF exchange is calculated using KS orbitals so that EXX energy will be slightly higher than the HF energy. The orbital-dependent exact-exchange (EXX) group of methods has received much attention in the literature. Two advantages of the EXX functional are often mentioned: (a) the self-interaction correction is incorporated in this functional; (b) it is natural to break up the total problem of electron–electron interaction in the large (due to self-interaction correction) exchange part and the small correlation part. The hope is of course that it will be simpler to find an accurate density-functional for the small correlation energy.

A critique of the EXX method in DFT can be found, for example, in [327, 355]. It is clear that the EXX method does not offer any advantage over HF for energies. On the contrary, starting with EXX actually undermines the very basis of the success of DFT, which has been the breaking away from the quantum-chemistry paradigm of dividing up the full electron–electron interaction problem into two steps: first Hartree–Fock (or exchange only) and next the remaining correlation problem. That this is indeed the case is masked by the DFT terminology that still uses the names “exchange” (*e.g.*, Becke exchange, Perdew exchange) and “correlation” (*e.g.*, Perdew–Wang correlation, Lee–Yang–Parr (LYP) correlation). One should be aware that, while correlation is indeed much smaller than exchange in for instance (heavy) atoms, this is not true in the electron-pair bond. Both Hartree–Fock and the use of the exact-exchange functional in Kohn–Sham DFT are very deficient models for the description of chemical bonding. They both use a two-particle probability distribution that is wrong, as can be seen from the shape of the “hole,” a reference electron creates around itself: the hole is not centered around the reference electron but is delocalized over the atoms forming the bond. From this wrong hole shape, one can understand the deficiencies of this model, such as too diffuse orbitals and

density, hence wrong kinetic energy and electron–nuclear attraction energy. The true xc hole is substantially more localized around the reference electron. That is why rough localized model holes, like those of GGA, which approximate this total hole, are so successful.

This can be illustrated for the prototype electron-pair bond, the H_2 molecule, at the equilibrium H–H distance [327, 355]: in the H_2 case, HF and EXX are identical. The Hartree–Fock (EXX) model is a poor zero-order approximation for the electron-pair bond. It is also extremely size inconsistent, in the sense that when we introduce a second H atom in the universe, remote from a given H atom, the HF/EXX model totally fails to deliver the sum of the energies of two H atoms. However, when we add the Coulomb hole (or correlation hole) to the Fermi (exchange) hole, we obtain a total hole that is localized at the nucleus where the reference electron is located. This will provide the right potential and therefore the right density and kinetic energy. The localized hole does not require any knowledge of where the other H atom is located; it is the unphysical breaking up of this total hole into a delocalized exchange part and an equally delocalized Coulomb part that complicates the electron–electron interaction treatment and requires knowledge of the position of the second nucleus in order to build accurate holes. Actually, this example illustrates that the division in exchange and correlation holes creates one of the largest problems of DFT. The problem basically is that the total density $\rho(\mathbf{r})$ around each H nucleus is identical at large H–H distances to that in a free H atom. However, the exchange and correlation energies in the stretched H_2 are very different from those in two isolated H atoms. In particular, the correlation energy is zero in individual H atoms, in contrast to the strong left–right nondynamical correlation in the dissociating H_2 molecule. It is virtually impossible to devise functionals that use only local information (local density and derivatives of the density) and still recognize the position of the other H atom and build correctly the individual exchange and correlation holes, the shape of which is determined by the positions of the nuclei. The LDA and GGA total holes are localized around the reference electron, which is a definite advantage, and the EXX approximation cannot be regarded to be the next improvement beyond GGA. There are other possibilities of such an improvement: (1) to develop orbital-dependent functionals, which represent exchange and correlation simultaneously, and (2) use HF–DFT exchange mixing.

The first possibility was realized recently in [355–358] where the virtual orbital-dependent xc functional E_{xc}^{BB} (BB, Buijse–Baerends) is suggested:

$$E_{xc}^{BB}[\{\varphi_j\}, \{\varphi_a\}] = -\frac{1}{2} \sum_i^M \sum_j^M \sqrt{w_i w_j} \int d\mathbf{r}_1 d\mathbf{r}_2 \frac{\varphi_i(\mathbf{r}_1) \varphi_i(\mathbf{r}_2) \varphi_j(\mathbf{r}_1) \varphi_j^*(\mathbf{r}_2)}{r_{12}} \quad (7.37)$$

and applied in calculations of hydrogen chains H_n and small molecules. Here $w_i[\rho]$ is the xc orbital weight, which governs the involvement of the occupied/virtual orbital φ_i in the xc functional. It is important that the summation in (7.37) is made over $M = N_{occ} + N_v$ orbitals where N_{occ} and N_v are the numbers of occupied and

virtual KS orbitals. By giving weights to the virtual orbitals, one can incorporate the effect of correlation. In [356], the functional form of w_i has been approximated with the Fermi-type distribution:

$$w_i = \frac{2}{1 + \exp(f(\varepsilon_i - \varepsilon_F))} \quad (7.38)$$

where ε_i are the KS orbital energies and ε_F is the Fermi-level parameter. We do not consider the E_{xc}^{BB} functional in more detail as its possibilities for crystals are not well studied.

The second possibility of GGA improvement—mixing of HF and DFT exchange—is used in the well-known B3LYP, B3PW, and PBE0 hybrid functionals. The performance of hybrid density functionals (HDF) in solid-state chemistry is examined in a review [359] and many original publications. It is demonstrated that the HDF methods allow calculation of different properties of solids in good agreement with the experiment. We return to this point in Sect. 7.2. In Kohn–Sham density-functional theory, the exchange-correlation energy is rigorously given by

$$E_{xc} = \frac{1}{2} \int \rho(\mathbf{r}) \int \frac{h_{xc}(\mathbf{r}, \mathbf{r}')}{|\mathbf{r}' - \mathbf{r}|} d^3\mathbf{r}' d^3\mathbf{r} \quad (7.39)$$

$$h_{xc}(\mathbf{r}, \mathbf{r}') = \int_0^1 h_{xc}^\lambda(\mathbf{r}, \mathbf{r}') d\lambda \quad (7.40)$$

known as the “adiabatic connection” or “coupling-strength integration.” In this most fundamental of DFT formulas, h_{xc} is an effective exchange-correlation hole, and λ is a coupling-strength parameter that switches on interelectronic $1/r_{12}$ repulsion, subject to a fixed electronic density (achieved, in principle, by suitably adjusting the external potential as a function of λ). The Kohn–Sham h_{xc} is therefore a coupling-strength average of h_{xc}^λ as it evolves from $\lambda = 0$ through $\lambda = 1$ [360].

In an atom, the size of the hole is relatively insensitive to λ and remains of roughly atomic size. In a molecule, the changes in the character and size of the hole occur as λ varies from its noninteracting $\lambda = 0$ to its fully interacting $\lambda = 1$ limits. At $\lambda = 0$ (pure exchange with no correlation whatsoever) delocalization of the hole over two or more centers is characteristic. Accurate DFTs must recognize this $\lambda = 0$ nonlocality. As λ increases, the hole is localized by the long-range, nondynamical, left–right correlations that are absent in atoms but operative in molecules. At the fully interacting limit ($\lambda = 1$), the hole has been localized to roughly atomic size. To incorporate the necessary nonlocality, Becke [361] proposed so-called hybrid functionals:

$$E_{xc}^{hyb} = E_{xc}^{KS} + a_{mix} (E_x^{HF} - E_x^{KS}) \quad (7.41)$$

The difference from the EXX functional is the following: the exact HF exchange E_x^{HF} is mixed with the DFT (LDA,GGA) exchange-correlation energy in hybrid

functionals and with the DFT correlation energy in EXX functionals. The mixing parameter a_{mix} is used to patch an appropriate amount of HF exchange into the exchange-correlation energy. Even the simplest “half–half” hybrid functional ($a_{\text{mix}} = 0.5$) greatly improves the calculated properties, compared with the pure DFT results. Becke developed the 3-parameter functional expressions known as B3PW and B3LYP hybrid functionals:

$$E_{\text{xc}}^{\text{B3PW}} = E_{\text{xc}}^{\text{LSDA}} + a (E_{\text{x}}^{\text{HF}} - E_{\text{x}}^{\text{LSDA}}) + b \Delta E_{\text{x}}^{\text{Becke}} + c \Delta E_{\text{x}}^{\text{PW}} \quad (7.42)$$

$$E_{\text{xc}}^{\text{B3LYP}} = E_{\text{xc}}^{\text{LSDA}} + a (E_{\text{x}}^{\text{HF}} - E_{\text{x}}^{\text{LSDA}}) + b \Delta E_{\text{x}}^{\text{Becke}} + c \Delta E_{\text{x}}^{\text{LYP}} \quad (7.43)$$

The B3PW functional (7.42) uses in E_{xc} the Becke [346] exchange and Perdew–Wang exchange-correlation [343], while in the B3LYP functional (7.43), the correlation part is that suggested by Lee–Yang–Parr [347]. The a, b, c parameters were optimized to fit the experimental data and do not depend on the molecule under consideration. It is clear that the choice of hybrid functionals is motivated by reasonable physical arguments. The term $a (E_{\text{x}}^{\text{HF}} - E_{\text{x}}^{\text{LSDA}})$ replaces some electron-gas exchange with the exact exchange to capture the proper small- λ limit in (7.39). The coefficient a reflects the rate of onset correlation as it increases from zero. The other terms allow optimum admixtures of exchange and correlation-type gradient corrections. These hybrid functionals are the simplest mixture of exact exchange, the LSDA for exchange-correlation, and gradient corrections of exchange and correlation type that exactly recovers the uniform electron-gas limit. The B3LYP functional is the most popular in molecular quantum chemistry. Nevertheless, the correct amount of HF exchange included in any hybrid functional cannot be a constant over all species or even all geometries of a single species [362]. The rationale for mixing exact exchange with DFT approximation is discussed in [363]. The authors write the hybrid functional in the form

$$E_{\text{xc}} \cong E_{\text{xc}}^{\text{KS}} + \frac{1}{n} (E_{\text{x}} - E_{\text{x}}^{\text{KS}}) \quad (7.44)$$

where the optimum integer n can be found from the perturbation theory and $n = 4$ for atomization energies of typical molecules. Such a formally parameter-free hybrid functional with a PBE exchange-correlation part is known as the PBE0 hybrid functional. The simplification of hybrid exchange-correlation functionals was suggested by Becke [360] based on simulation of delocalized exact exchange by local density functionals. A simple model was introduced that detects exchange hole delocalization in molecules through a local variable related to kinetic-energy density.

Is it possible to use for extended systems (crystalline solids) the same hybrid functionals that are used in molecular DFT calculations? This problem is discussed in the next section.

7.2 Density-Functional LCAO Methods for Solids

7.2.1 *Implementation of Kohn–Sham LCAO Method in Crystal Calculations*

Although the same fundamental theory underlies the density-functional approach in both solid-state physics and molecular quantum chemistry and the same exchange-correlation functionals can be used in both disciplines (see Sect. 7.2.4), the detailed implementation is usually quite different [364]. First, this difference concerns the basis-set choice. Since the electronic charge density of an isolated molecule is necessarily localized in a finite region of space, the traditional quantum-chemical method is LCGTO (MOs are expanded in a basis of localized Gaussian-type orbitals, centered on the atomic nuclei). In contrast, the tradition in solid-state physics is to use plane waves (PW) as a basis set for expanding the one-particle Kohn–Sham wavefunctions (crystalline orbitals). These can be used in their pure form in the first-principles pseudopotential method [365] or modified near the atomic cores (augmented plane waves <http://www.wien2k.at>). The all-electron (termed also full potential—FP) PW calculations are practically difficult as the core-state description requires a huge number of plane waves. The plane waves are a reasonable first approximation to conduction-band eigenfunctions and permit many formal simplifications and computational economies. Nevertheless, PW methods have the disadvantage that very localized or inhomogeneous systems may require excessive numbers of waves for their representation. This problem can be especially serious in surface calculations, where the requirement of periodicity in three dimensions leads to a model with slabs repeating periodically along the surface normal. If the space between the slabs is wide enough to make interactions between them negligible, the “lattice constant” normal to the surface has to be quite large and the corresponding reciprocal lattice vector quite short, resulting in a large number of plane waves within a given kinetic-energy cutoff and hence a relatively expensive calculation. This problem is discussed in Chap. 11 in more detail.

The distance between the slabs needs to be even larger if adsorbate molecules are to be added to the surface, since these molecules also should not interact across the space between the slabs. Localized basis approaches to periodic systems do not suffer from this disadvantage. Very localized states, including core states if desired, can be represented by a suitable choice of atom-centered basis functions. The electronic charge density goes naturally to zero in regions of space where there are no atoms, and the lack of basis functions in such regions is not a problem unless a detailed description of energetic excitations, scattering states, or tunneling is required [364]. For surface modeling, there is no need for periodicity normal to the surface; a single slab of sufficient finite thickness can be used, since these methods can be formulated equally easily for systems periodic in one, two, or three dimensions. This facilitates the accurate treatment of molecule–surface interactions, especially when the molecules are relatively far from the surface. Also,

if the basis functions are carefully constructed and optimized for the crystalline environment (we discuss this problem in Chap. 8), it is possible to represent the valence-electron eigenstates with a relatively small number of basis functions: just enough to accommodate all the electrons, plus a few more functions to give the Kohn–Sham orbitals sufficient variational freedom. Thus, only a few tens of basis functions per atom are typically needed, versus hundreds per atom in typical plane-wave approaches. The auxiliary basis sets needed to represent the charge density and, if desired, the exchange-correlation potential are also fairly modest in size. Once the basis set has been constructed and the required overlap and Hamiltonian matrices formed, the small (compared to plane wave) size of the basis can greatly reduce the computational cost of solving the Kohn–Sham equations.

Also, especially in systems with large unit cells, one can exploit scarcity in these matrices, since basis functions on distant centers will have negligible overlap and interaction (except for certain long-range Coulomb multipole interactions that can be summed, according to Ewald’s convention, or screened). Advanced techniques can be applied to calculate multicenter integrals in LCGTO methods for solids. For example, in the implementation of periodic boundary conditions in the MO LCAO program [366, 367], all terms contributing to the KS Hamiltonian are evaluated in real space, including the infinite Coulomb summations, which are calculated with the aid of the fast multipole method [368, 369]. In LCGTO methods with PBC, the $O(N)$ linear-scaling DFT calculations for large and complex systems are possible [366, 370]. For example, carbon nanostructures up to C540 were calculated [371] using DFT LCAO with the numerical atomic basis. Below, we present the basic formalism for DFT KS equations for periodic systems using a basis set of atomic orbitals. For more details of DFT LCAO methods, the reader is referred to the original publications [364, 372–376].

The HF LCAO method for periodic systems was considered in Sects. 4.1.5 and 4.1.6. We discuss here the KS LCAO method for crystals in comparison with the HF LCAO approach. The electronic energy of the crystal (per primitive cell) as calculated within the HF approximation (E_{HF}) and DFT (E_{DFT}) can be expressed in terms of the one-electron density matrix (DM) of the crystal defined as $P(\mathbf{k})$ in terms of Bloch sums of AOs, (4.125), or as $\rho(\mathbf{R}, \mathbf{R}')$ in coordinate space, (4.126). These expressions are

$$E_{\text{HF}}[\rho] = E_0[\rho] + E_{\text{H}}[\rho] + E_{\text{X}}[\rho] \quad (7.45)$$

$$E_{\text{DFT}}[\rho] = E_0[\rho] + E_{\text{H}}[\rho] + E_{\text{XC}}[\rho] \quad (7.46)$$

where $E_0[\rho]$ is defined as the expectation value of the one-electron operator $\hat{h}(\mathbf{R})$

$$E_0[\rho] = \frac{1}{N} \int_{V_N} d^3 \mathbf{R} [\hat{h}(\mathbf{R}) \rho(\mathbf{R}, \mathbf{R}')]_{\mathbf{R}'=\mathbf{R}} \quad (7.47)$$

$E_H[\rho]$ is the Coulomb (Hartree) energy,

$$E_H[\rho] = \frac{1}{N} \int_{V_N} d^3 \mathbf{R} \int_{V_N} d^3 \mathbf{R}' \frac{\rho(\mathbf{R}, \mathbf{R}) \rho(\mathbf{R}', \mathbf{R}')}{|\mathbf{R} - \mathbf{R}'|} \quad (7.48)$$

$E_X[\rho]$ is the HF exchange energy,

$$E_X[\rho] = -\frac{1}{2N} \int_{V_N} d^3 \mathbf{R} \int_{V_N} d^3 \mathbf{R}' \frac{|\rho(\mathbf{R}, \mathbf{R}')|^2}{|\mathbf{R} - \mathbf{R}'|} \quad (7.49)$$

and $E_{XC}[\rho]$ in (7.46) is the exchange-correlation energy functional of density $\rho(\mathbf{R}, \mathbf{R}) = \rho(\mathbf{R})$ (different expressions for this functional depend on the DFT version and were discussed in Sect. 7.1). As in Sect. 4.3.1, the electron position vector $\mathbf{R}$ is supposed to be written as the sum $\mathbf{R} = \mathbf{r} + \mathbf{R}_n$, where $\mathbf{R}_n$ specifies the primitive cell and $\mathbf{r}$ is the position vector of an electron within this primitive cell. The difference between the HF exchange energy E_X and DFT exchange-correlation energy E_{XC} is the following: the former depends on the total DM $\rho(\mathbf{R}, \mathbf{R}')$, and the latter only on DM diagonal elements $\rho(\mathbf{R})$, *that is*, electron density.

In the HF approximation and DFT, the crystal orbitals are solutions to the equations:

$$\hat{F}(\mathbf{k}) \varphi_i(\mathbf{k}) = \varepsilon_i(\mathbf{k}) \varphi_i(\mathbf{k}) \quad (7.50)$$

where the one-electron operator $\hat{F}(\mathbf{k})$ is either the HF operator, $\hat{F}^{\text{HF}}(\mathbf{k})$

$$\hat{F}^{\text{HF}}(\mathbf{k}) = \hat{H}(\mathbf{k}) + \hat{J}(\mathbf{k}) + \hat{X}(\mathbf{k}) \quad (7.51)$$

or the Kohn–Sham operator $\hat{F}^{\text{KS}}(\mathbf{k})$,

$$\hat{F}^{\text{KS}}(\mathbf{k}) = \hat{H}(\mathbf{k}) + \hat{J}(\mathbf{k}) + \hat{V}_{\text{XC}}(\mathbf{k}) \quad (7.52)$$

Here, $\hat{H}(\mathbf{k})$ is a one-electron operator that describes the motion of an electron in the crystal and is equal to the sum of the kinetic-energy operator and the Coulomb interaction operator between the electron and fixed atomic nuclei and $\hat{J}(\mathbf{k})$ and $\hat{X}(\mathbf{k})$ are the Coulomb and exchange operators, respectively, which describe the interaction of the given electron with the other electrons of the crystal.

In the LCAO basis, both the Hartree–Fock and Kohn–Sham equations are the same (see (4.57)):

$$F(\mathbf{k})C(\mathbf{k}) = S(\mathbf{k})C(\mathbf{k})E(\mathbf{k}) \quad (7.53)$$

The HF and KS operators in the reciprocal space are represented by the Fock matrices $F_{\mu\nu}^{\text{HF}}(\mathbf{k})$ and Kohn–Sham matrices $F_{\mu\nu}^{\text{KS}}(\mathbf{k})$, which are related to the matrices in the coordinate space by the relations

$$F_{\mu\nu}^{\text{HF}}(\mathbf{k}) = \sum_{\mathbf{R}_n} \exp(i\mathbf{k} \cdot \mathbf{R}_n) [h_{\mu\nu}(\mathbf{R}_n) + j_{\mu\nu}(\mathbf{R}_n) + x_{\mu\nu}(\mathbf{R}_n)] \quad (7.54)$$

$$F_{\mu\nu}^{\text{KS}}(\mathbf{k}) = \sum_{\mathbf{R}_n} \exp(i\mathbf{k} \cdot \mathbf{R}_n) [h_{\mu\nu}(\mathbf{R}_n) + j_{\mu\nu}(\mathbf{R}_n) + v_{\mu\nu}^{\text{XC}}(\mathbf{R}_n)] \quad (7.55)$$

where $h_{\mu\nu}(\mathbf{R}_n)$, $j_{\mu\nu}(\mathbf{R}_n)$, and $x_{\mu\nu}(\mathbf{R}_n)$ are the one-electron, Coulomb, and exchange parts of the Fock matrix in the coordinate space, respectively (see (4.59)–(4.63)). In the DFT, instead of the nonlocal-exchange interaction matrix $x_{\mu\nu}(\mathbf{R}_n)$, the exchange-correlation matrix $v_{\mu\nu}^{\text{XC}}(\mathbf{R}_n)$ is used, with different exchange-correlation functional approximations being employed in various versions of the DFT. In particular, in the local-density approximation (LDA), it is assumed that

$$v_{\mu\nu}^{\text{XC}}(\mathbf{R}_n) = \int d^3\mathbf{R} \varphi_{\mu}(\mathbf{R}) v^{\text{XC}}(\mathbf{R}) \varphi_{\nu}(\mathbf{R} - \mathbf{R}_n)$$

$$v^{\text{XC}}(\mathbf{R}) = \frac{\partial}{\partial \rho} \varepsilon[\rho(\mathbf{R})] \quad (7.56)$$

The CO LCAO calculations based on both the HF method and DFT allow one not only to make a comparison between the results obtained within these two approximations but also to employ a combination of these approximations used in hybrid HF–DFT methods. The HF self-consistent electron density of the crystal can be used to calculate correlation corrections to the total HF energy *a posteriori* [377]. In some cases, it is useful to use the HF self-consistent density matrix to make the convergence of the DFT LCAO self-consistent procedure faster [21].

The extension of the existing HF LCAO computer codes to DFT LCAO ones allows a very direct comparison between these methods using the same code, the same basis set, and the same computational conditions. The modification of the HF LCAO code with PBC to perform DFT calculations is straightforward in principle. It is required only to delete the HF exchange and instead to evaluate the matrix elements of exchange-correlation operator, that is, to solve KS rather than HF equations in each iteration of the SCF procedure [376]. These modifications were made in the PBC HF codes CRYSTAL95 [21] and GAUSSIAN03 [102]. The main difficulty of this modification arises in the calculations of matrix elements of the exchange-correlation operator. Different approaches to this problem were suggested. The principal merit of the HF LCAO scheme is the possibility to calculate the matrix elements of the Fock matrix analytically. This merit may be retained in the DFT LCAO calculation if the exchange-correlation potential is expanded in an auxiliary basis set of Gaussian-type functions, with even-tempered exponents. At each SCF iteration, the auxiliary basis set is fitted to the actual analytic form of the exchange-correlation potential, which changes with the evolving charge density [378].

The numerical integration also can be used to calculate the matrix elements of the exchange-correlation potential. For the numerical integration, the atomic partition method proposed by Savin [379] and Becke [380] has been adopted and combined

with Gauss–Legendre (radial) and Lebedev (angular) quadratures [381]. The Kohn–Sham LCAO periodic method based on numerical integration at each cycle of the self-consistent field process is computationally more expensive than the periodic LCAO Hartree–Fock method that is almost fully analytical.

In conclusion of this section, we give some comments concerning the meaning of the KS eigenvalues and orbitals [11]. Strictly speaking, the KS eigenvalues and eigenvectors do not have the physical meaning of one-electron energies and wavefunctions as in the HF theory. Also, the single-determinant many-electron wavefunction constructed out of the KS orbitals does not correspond to the exact wavefunction of the system of interacting electrons; it is merely a wavefunction of the corresponding fictitious noninteracting system. The HF eigenvalues for occupied and empty states are calculated with different potentials, but KS eigenvalues with the same. Therefore, one should be careful with the KS eigenvalues of the states lying above the “occupied” ones. For example, the energy gap between the uppermost valence and the lowermost conduction bands in a solid is strongly underestimated in the majority versions of DFT. Note that the gap is always overestimated in the HF theory. It can be shown that similarly to Koopman’s theorem in the HF theory, the ionization energy in the KS theory is given by the KS energy in the highest-occupied state. But this result cannot be applied to other occupied KS states since in the KS theory, all states must be occupied sequentially from the bottom to the top: one cannot remove an electron below the highest-occupied state leaving a hole there.

As an advantage of the DFT LCAO method, one can mention the possibility of linear scaling in calculations of complex molecules and crystals, considered in next section.

7.2.2 Linear-Scaling DFT LCAO Methods for Solids

The increase in computer power and the progress in the methodology have allowed the *ab initio* calculations of increasingly more complex and larger systems with an increasing number of atoms N (for periodic systems N is the number of atoms in the primitive unit cell). In the HF LCAO and DFT PW methods, the computer time and memory scales with N like N^{2-3} [365, 386], inner only recently that two linear system-size scaling $O(N)$ DFT LCAO methods for periodic systems were developed that resulted in general-purpose, flexible DFT computer codes (<http://www.uam.es/departamentos/ciencias/fismateriac/siesta/>) [102].

The *SIESTA* (Spanish Initiative for Electronic Simulations with Thousands of Atoms) method [370, 371, 387] achieves linear scaling by the explicit use of localized Wannier-like functions and numerical pseudoatomic orbitals confined by a spherical infinite-potential wall [388]. As the restriction of the *SIESTA* method we mention the difficulty of the all-electron calculations and use of only LDA/GGA exchange-correlation functionals.

The second DFT LCAO linear-scaling method by Scuseria and Kudin (SK method) [366] uses Gaussian atomic orbitals and a fast multipole method, which achieves not only linear-scaling with system size but also very high accuracy in all infinite summations [384]. This approach allows both all-electron and pseudopotential calculations and can be applied also with hybrid HF–DFT exchange-correlation functionals.

The first step in the *SIESTA* method calculation is the choice of pseudopotentials. In Chap. 8, we discuss in more detail the pseudopotentials used in periodic HF and KS LCAO calculations. The *SIESTA* method relies on the use of strictly confined basis atomic orbitals, *that is*, orbitals that are zero beyond a certain radius. This keeps the energy strictly variational, thus facilitating the test of the convergence with respect to the radius of confinement. In addition to the atomic valence orbitals, polarization pseudoatomic orbitals are added to account for the deformation induced by bond formation. The different AO choices in HF and DFT LCAO calculations are discussed in Chap. 8. In calculations of silicon crystal, it was shown [387] that the standard basis already offers quite well-converged results, comparable to those used in practice in most plane-wave calculations. The study of the dependence of the lattice constant, bulk modulus, and cohesive energy of bulk silicon on the range of the basis orbitals shows that a cutoff radius of 3 Å for both *s* and *p* orbitals already yields very well-converged results.

Within the pseudopotential approximation, the standard KS one-electron Hamiltonian is written as

$$\hat{H} = \hat{T} + \sum_I \hat{V}_I^{\text{loc}} + \sum_I \hat{V}_I^{\text{nonloc}} + \hat{V}_H + \hat{V}_{\text{xc}} \quad (7.57)$$

where $\hat{T}$ is the kinetic energy operator, *I* is an atom index, and $\hat{V}_H$ and $\hat{V}_{\text{xc}}$ are the total Hartree and *xc* potentials. The pseudopotential operator is the sum of the local $\hat{V}_I^{\text{loc}}$ and nonlocal $\hat{V}_I^{\text{nonloc}}$ parts of the pseudopotential of atom *I*. The nonlocal part uses a different radial potential $V_l(r)$ for each angular momentum *l* (see Chap. 8). In order to eliminate the long range of V_l^{loc} , it is screened with the potential V_l^{at} , created by an atomic electron density ρ_l^{at} , and constructed by populating the basis functions with appropriate valence atomic charges. Notice that since the atomic basis orbitals are zero beyond the cutoff radius r_l^c , the screened “neutral-atom” (NA) potential $V_I^{\text{NA}} = V_I^{\text{loc}} + V_I^{\text{nonloc}}$ is also zero beyond this radius. Now, let $\delta\rho(\mathbf{r})$ be the difference between the self-consistent electron density $\rho(\mathbf{r})$ and the sum of atomic densities $\rho^{\text{at}} = \sum_I \rho_l^{\text{at}}$, and let $\delta V^H(\mathbf{r})$ be the electrostatic potential generated by $\delta\rho(\mathbf{r})$ that integrates to zero and is usually much smaller than $\rho(\mathbf{r})$. Then the total Hamiltonian may be rewritten as

$$\hat{H} = \hat{T} + \sum_I \hat{V}_I^{\text{nonloc}} + \delta V_H + V_{\text{xc}} \quad (7.58)$$

The matrix elements of the first two terms involve only two-center integrals that are calculated in reciprocal space and tabulated as a function of interatomic distance.

The remaining terms involve potentials that are calculated on a three-dimensional real-space grid.

In the Brillouin sampling, a supercell around the unit cell (and comprising the unit cell itself) is defined large enough to contain all the atoms whose basis orbitals are nonzero at any of the grid points of the unit cell or that overlap with any of the basis orbitals in it. All the nonzero two-center integrals between the unit-cell basis orbitals and the supercell orbitals are calculated without any complex phase factors. Also calculated are the grid integrals between *all* the supercell basis orbitals $\varphi_{\mu'}$ and $\varphi_{\nu'}$ (primed indices run over all the supercell), but *within the unit cell only*. These integrals are accumulated in the corresponding matrix elements. Once all the real overlap and Hamiltonian matrix elements are calculated, they are multiplied, at every $\mathbf{k}$ point, by the corresponding phase factors and accumulated by folding the supercell orbital to its unit-cell counterpart. The resulting $N \times N$ complex eigenvalue problem, with N the number of orbitals in the unit cell, is then solved at every sampled $\mathbf{k}$ -point, finding the Bloch-state expansion coefficients over AOs and the density at a grid point of the unit cell. The fineness of this grid is controlled by a $\mathbf{k}$ -grid cutoff (see Sect. 4.2), a real-space radius that plays a role equivalent to the plane-wave cutoff of the real-space grid [84]. The origin of the $\mathbf{k}$ -grid may be displaced from $\mathbf{k} = \mathbf{0}$ in order to decrease the number of inequivalent $\mathbf{k}$ -points (see Sect. 4.2.3). If the unit cell is large enough to allow a Γ -point-only calculation, the multiplication by phase factors is skipped, and a single real-matrix eigenvalue problem is solved (in this case, the real-matrix elements are accumulated directly in the first stage, if multiple overlaps occur).

To solve the KS equations in $O(N)$ operations, the localized, Wannier-like states are used as they are constrained by their own localization region. Each atom I is assigned a number of states equal to $\text{int}(Z_I^{\text{core}}/2 + 1)$ so that, if doubly occupied, they can contain at least one excess electron (they can also become empty during the minimization of the energy functional). These states are confined to a sphere of radius R_c (common to all states) centered at nuclei I . Irrespective of whether the $O(N)$ functional or the standard diagonalization is used, an outer self-consistency iteration is required, in which the density matrix is updated. Even when the code is strictly $O(N)$, the CPU time may increase faster if the number of iterations required to achieve the solution increases with N . In fact, it is a common experience that the required number of self-consistency iterations increases with the size of the system. This is mainly because of the “charge-sloshing” effect, in which small displacements of charge from one side of the system to the other give rise to larger changes of the potential as the size increases. Fortunately, the localized character of the Wannier-like wavefunctions used in the $O(N)$ method also helps to solve this problem, by limiting the charge sloshing. Figure 7.1 shows the essentially perfect $O(N)$ behavior of the overall CPU time and memory in silicon supercells of 64, 512, 1,000, 4,096, and 8,000 atoms calculations [387].

The SIESTA method provides a very general scheme to perform a range of calculations from very fast to very accurate, depending on the needs and stage of the simulation, of all kinds of molecule, material, and surface. It allows DFT simulations of more than a thousand atoms in modest PC workstations and over

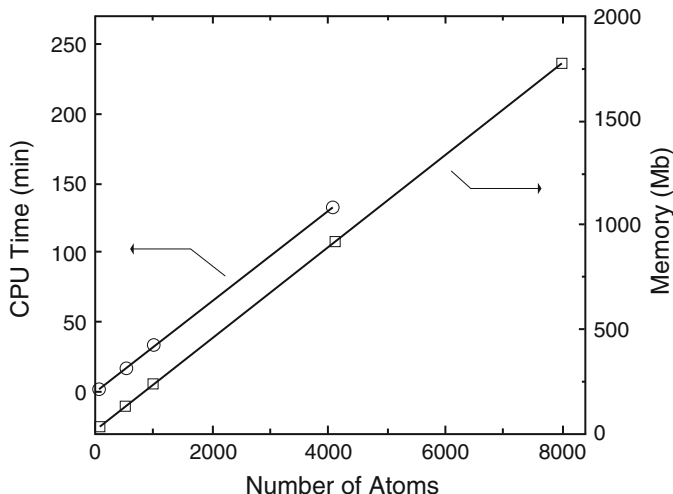


Fig. 7.1 $O(N)$ behavior of the overall CPU time and memory in silicon supercell calculations [387]

a hundred thousand atoms in parallel platforms [387]. The numerous applications of the SIESTA DFT LCAO method can be found on the SIESTA code site (<http://www.uam.es/departamentos/ciencias/fismateriac/siesta/>). These applications include nanotubes, surface phenomena, and amorphous solids.

The *Scuseria–Kudin* method of $O(N)$ scaling is due to the use of efficient direct lattice summation. The simulations of systems with periodic boundary conditions include the long-range Coulomb potential. To properly converge the resulting infinite Coulomb sum, the Ewald summation method is adequate [68]. In this approach, one part of the Coulomb contribution is computed in direct space and another in reciprocal space. The Ewald summation method yields $O(N^{3/2})$ or $O(N \log N)$ with the fast Fourier transform [369]. Alternatively, the infinite summation can be done using the periodic fast multipole method (FMM) [382,383], carried out entirely in direct space. The periodic FMM was extended to energy calculations for periodic systems with Gaussian charge distributions [369,384] and demonstrated $O(N)$ scaling properties for the algorithm. In this particular situation, the FMM has certain advantages over the Ewald summation such as its universal applicability to systems periodic in one, two, and three dimensions. The FMM method was extended also to the analytic calculation of the stress tensor whose components are required for energy optimization with respect to particle positions in the unit cell and the lattice dimensions [385]. The FMM partitions all pair interactions into near-field and far-field, and evaluates these contributions in CPU times that are approximately constant per particle, yielding an $O(N)$ algorithm. In the FMM, the system under consideration is embedded in a hierarchy of 8^n cubic boxes at the finest mesh level, where n specifies the total number of tiers [389, 390]. All charge distributions located in a given box are represented by

multipole expansions about the center of the box. For highly accurate results, the near-field (NF) portion of the problem, which is defined by interactions inside a given box and neighboring boxes, is treated exactly. Interactions in the far-field (FF) are treated through multipole expansions. The distinctive characteristic of the FMM is that translation techniques allow these multipole expansions to interact at different mesh levels (depending on the distance between their centers) through an upward and downward pass of the tree hierarchy, yielding a method with effective linear scaling.

In the Gaussian FMM (GFMM) implementation, a given interaction is included in the FF only if the number of boxes separating the edge of the boxes containing the two charge distributions is larger than the sum of the ranges of the distributions. For Gaussian functions, the range definition can be derived from the basic Coulomb integral between two s -type distributions as $r = (2s)^{-1/2} \text{erfc}^{-1}(\varepsilon)$ where s is the exponent of the product Gaussian distribution, erfc^{-1} is the inverse of the complementary error function, and ε is the desired error in the approximation. The real number is rounded up to the nearest integer, thus guaranteeing an error smaller than ε . The electron–electron near-field (NF) interactions were treated exactly through six-dimensional analytic integration of Gaussian functions. The maximum l of a given multipole expansion was truncated to an effective value l_{eff} based on $\varepsilon = k(a/R)^{l_{\text{eff}}}$, where ε is the desired accuracy, a is a constant whose optimum value is 0.63, and k is adjusted such that $l_{\text{eff}} = l_{\text{max}}$, when $R = 3$ boxes. This simple formula is straightforward, substantially improves the speed of the GFMM (which asymptotically scales as N), and still yields very accurate results. This “very fast” approach is partially responsible for the good scaling properties of the GFMM used in the SK $O(N)$ approach. The use of the GFMM for electrostatic interactions allows the infinite lattice sums to be computed exactly for systems of any periodicity. Calculations of energy derivatives with the FMM in periodic systems are similar to those in molecules.

In the SK DFT PBC implementation, as much work as possible is done in real space. Consequently, all matrices are stored in real-space form and transformed into $\mathbf{k}$ space only when needed. In the iterative part of the code, first the entire real-space Fock matrix $F_{\mu\nu}^{oR_n}$ is constructed, it is transformed into several $\mathbf{k}$ -space matrices, which are diagonalized to obtain orbital coefficients and energies, and then the reciprocal-space density matrices are constructed. The latter are integrated by numerical means to yield the real-space density matrix that is used in the following SCF cycle. The gradient part of the code also deals with real-space quantities only. Overall, $\mathbf{k}$ -space integration adds just a few extra steps to the PBC calculation when compared to the molecular case.

All the transformations between real and reciprocal spaces are computationally inexpensive and simple to implement. An extremely important feature of the SK direct-space Gaussian PBC method is that once the real-space matrices are available, the major cost of any additional $\mathbf{k}$ -point calculation is just the transformation into an orthonormal basis set plus the diagonalization. This is drastically different from the PW implementations where one computes the Fock matrix for each $\mathbf{k}$ point separately. Even though the cost of such matrix formation may be considerably lower for

PWs than for the real-space Fock matrix, the relatively low cost of additional $\mathbf{k}$ -point calculations when using Gaussians permits denser $\mathbf{k}$ -point meshes in reciprocal space even for systems of medium size. Furthermore, the derivatives of the band energies with respect to the $\mathbf{k}$ vector are also rather straightforward to compute. Such information may be very useful in the Brillouin-zone integration for systems with complicated band structures. In order to reduce the number of SCF cycles, the direct inversion of the iterative subspace method (DIIS), developed by Pulay [391], has been used. DIIS requires formation of error matrices $R = (FPS - SPF)$ (F, P, S are Fock, density and overlap matrices, respectively) for each SCF cycle. The matrix R approaches zero as the calculation proceeds toward convergence. During the DIIS procedure, one evaluates the inner products of the error matrices from different SCF cycles, $B_{ij} = R_i R_j$ and uses these B_{ij} products to determine the DIIS mixing coefficients. A simple way to incorporate the DIIS procedure into a PBC code is to employ F, P , and S matrices just for one point in reciprocal space, for example, the Γ ($\mathbf{k} = \mathbf{0}$) point. For this point, the F, P , and S matrices are real, and all the DIIS steps are then the same as in the case of molecular calculations. The DIIS mixing coefficients, evaluated from matrices at $\mathbf{k} = \mathbf{0}$, are used to form the extrapolated real-space Fock matrix $\tilde{F}_{\mu\nu}^{0R_n}$ and Fock matrices in all $\mathbf{k}$ points through the extrapolation of the real-space $\tilde{F}_{\mu\nu}^{0R_n}$ matrix.

In periodic calculations, large basis sets with diffuse functions may cause instabilities in the SCF procedure due to the limited accuracy of the Fock-matrix construction, and much more rarely due to the limited accuracy of the diagonalization. The usual prescription for restoring the stability of the SCF procedure is to project out the orbitals with small overlap eigenvalues from the basis set, which can be done during the orthonormalization. In order to transform GTOs to an orthonormal basis, one may employ symmetric orthogonalization and use the $S^{-1/2}$ matrix. Another way to orthonormalize the basis set is called canonical orthogonalization and uses the matrix $U = VS^{-1/2}$ (V is the eigenvector matrix of the overlap matrix S). In calculations with PBC, the instabilities arise mainly from numerical inaccuracies on the Hamiltonian matrix formation rather than true linear dependences in the basis set [366]. Therefore, it is important in the SK method implemented in code [102] that kinetic and electrostatic contributions to the Fock matrix are evaluated exactly (the latter via FMM), while the DFT exchange-correlation quadrature is also carried out with high accuracy. Therefore, one might expect that the SCF instabilities would occur only for very small overlap matrix eigenvalues, somewhere in the 10^{-6} – 10^{-7} range. Indeed, this is the behavior observed in all the calculations [366].

The key issue in PBC calculations seems to be the Hamiltonian matrix evaluation, which needs to be done to very high accuracy, especially in the infinite Coulomb sums. This goal is achieved by means of the GFMM without resorting to any truncation. There are three major contributions to the Fock-matrix formation: the kinetic-energy term, the electrostatic term, and the exchange-correlation contribution. In large systems, the kinetic-energy matrix is sparse, computed only once, and is therefore easy to deal with. The electrostatic part of our code uses the

Table 7.1 IBM Power3 CPU times (sec) for PPV LSDA/3-21G [366]

$(\text{C}_8\text{H}_6)_x, x$	1	2	4	8	16
No. atoms	14	28	56	112	224
No. basis 84	168	336	672	1,344	
No. $\mathbf{k}$ points	16	8	4	2	1
No. FMM levels	3	4	5	6	7
Timings					
Form S^{-1} ^a	0.6	2.0	7	28	115
FMM, FF	1.3	2.5	5	10	20
FMM, NF	6.3	12.1	25	48	98
XC quad	13.0	26.4	54	109	223
DIIS	0.03	0.13	0.9	7.9	73
Γ diag	0.04	0.21	1.3	9.9	78
Diag ^a	0.91	3.2	12.3	52	198
Total SCF	197	416	935	2,342	7,285
Forces					
FMM, FF	2.7	5.4	11	21	43
FMM, NF	28.4	57.4	115	232	446
XC quad	24.1	49.4	106	243	621
Total force	55	113	233	500	1,123

^a Timings reported include all $\mathbf{k}$ points

periodic FMM, so its scaling is very close to linear. The periodic exchange-correlation quadrature is a straightforward extension of the one used in molecular calculations whose linear scaling has also been demonstrated [392]. Furthermore, the analytic gradient code resembles the Fock-matrix formation, and, therefore, the force calculation also has $O(N)$ computational cost. The density-matrix update is done in the conventional way, by diagonalizing the Kohn–Sham Hamiltonian matrix and constructing the density matrix from its eigenvectors. Although this procedure scales as $O(N^3)$, it has such a small scaling prefactor that the diagonalization cost for systems with up to a few thousand Gaussian basis functions is rather small compared to other steps in the PBC code.

For very large systems, the DIIS procedure uses sparse matrices, and therefore its cost also becomes close to linear. In order to demonstrate the actual scaling properties of SK DFT PBC code [102], a series of calculations have been carried out for PPV (paraphenylenevinylene) with a different number of monomers in the unit cell [366]. The results of these LSDA calculations are presented in Table 7.1. The SCF took 10 cycles to converge the density to a rms deviation of 10^{-8} . As is seen from Table 7.1 in the SCF part of the calculations, the CPU time required for the evaluation of electrostatic and exchange-correlation terms scales linearly for all practical purposes. On the other hand, the complex diagonalizations and the DIIS procedure scale as $O(N^3)$. The relative cost of all these $O(N^3)$ steps is such that for the largest system in Table 7.1 (224 atoms, 1,344 basis functions) the total CPU time is roughly similar to the CPU time required for the Fock-matrix formation.

The references to the recent applications of the SK method implemented in the GAUSSIAN03 code [102] can be found on the site <http://www.gaussian.com/gpeople/gus.htm> and in original papers.

The important advantage of the Scuseria–Kudin implementation of the DFT LCAO $O(N)$ method for solids is the possibility to use hybrid HF–DFT exchange–correlation functionals, including the recently developed screened Coulomb hybrid functional, discussed in the next subsection.

7.2.3 *Heyd–Scuseria–Ernzerhof Screened Coulomb Hybrid Functional*

In Sect. 7.1.5, we briefly discussed hybrid density functionals, which contain a portion of HF exchange and are popular in molecular quantum chemistry since they provide higher accuracy than LDA and GGA functionals. The idea of hybrid functionals is related to the adiabatic connection method (ACM), (7.40), which connects the noninteracting KS reference system to the fully interacting real system. The ACM (hybrid) functionals (7.41) include the coefficient a_{mix} of mixing HF and KS exchange. Perdew and coworkers have also shown [363] that this mixing coefficient value can be fixed a priori ($a_{\text{mix}} = 0.25$) taking into account that fourth-order perturbation theory is sufficient to get accurate numerical results for molecular systems. This leads to a family of adiabatic connection method functionals with the same number of adjustable parameters as their GGA’s constituents (ACM0 functionals, (7.44)). In particular, the PB0LYP variant gives results comparable to those of 3-parameter hybrids in B3LYP, whereas the modified mPW0PW functional gives results competitive with the B0LYP results [393]. The PBE0 hybrid functional [363] does not contain any adjustable parameter and proved to be successful in molecular calculations.

In solid-state calculations, however, the use of hybrid functionals is not a common practice because of the high computational cost that exact exchange involves. A recent alternative to conventional hybrid functionals is a screened exchange hybrid functional developed by Heyd, Scuseria, and Ernzerhof (HSE) [394,395]. This functional uses a screened Coulomb potential for the exact exchange interaction, drastically reducing its computational cost and providing results of similar quality to traditional hybrid functionals. It was demonstrated that the screened HF exchange (neglect of the computationally demanding long-range part of HF exchange) exhibits all physically relevant properties of the full HF exchange.

We discuss here the main features of the HSE hybrid functional and its application in solid-state LCAO calculations. The HSE functional for solids is much faster than regular hybrids and can be used in metals also.

The range of the exchange interaction in insulators decays exponentially as a function of the bandgap [396]. In metallic systems, the decay is algebraic. To render the HF exchange tractable in extended systems, either the exchange interactions

need to be truncated artificially or their spatial decay accelerated [395]. Various truncation schemes have been proposed to exploit the exponential decay in systems with sizable bandgaps [399–401]. Truncation schemes are very useful for systems with localized charge distributions where the HF exchange decays rapidly over distance. However, these approaches fail to significantly decrease the computational effort in systems with small or no gaps. In delocalized systems, truncation leads to severe convergence problems in the self-consistent field (SCF) procedure as well as uncertainties in the predicted energy of the system. The second option, accelerating the spatial decay, circumvents both of these problems but still neglects interactions that might be physically important. The HSE hybrid density functional includes the spatial decay acceleration using a screened Coulomb potential and attempts to compensate for the neglected interactions.

A screened Coulomb potential is based on a splitting of the Coulomb operator into short-range (SR) and long-range (LR) components. The choice of splitting function is arbitrary as long as SR and LR components add up to the original Coulomb operator. HSE use the error function to accomplish this split since it leads to computational advantages in evaluating the short-range HF exchange integrals: the error function can be integrated analytically when using Gaussian basis functions. The following partitioning is used for the full $1/r$ Coulomb potential:

$$\frac{1}{r} = \left(\frac{\operatorname{erfc}(\omega r)}{r} \right)_{\text{SR}} + \left(\frac{\operatorname{erf}(\omega r)}{r} \right)_{\text{LR}} \quad (7.59)$$

where the complementary error function $\operatorname{erfc}(\omega r) = 1 - \operatorname{erf}(\omega r)$ and ω is an adjustable parameter. For $\omega = 0$, the long-range term becomes zero and the short-range term is equivalent to the full Coulomb operator. The opposite is the case for $\omega \rightarrow \infty$. In the HSE approach, the screened Coulomb potential is applied only to the exchange interaction. All other Coulomb interactions of the Hamiltonian, such as the Coulomb repulsion of the electrons, do not use a screened potential. The exchange energy in the PBE0 functional $E_x^{\text{PBE0}} = a_{\text{mix}} E_x^{\text{HF}} + (1 - a_{\text{mix}}) E_x^{\text{PBE}} + E_c^{\text{PBE}}$ is split into short- and long-range components:

$$\begin{aligned} E_x^{\text{PBE0}} = & a_{\text{mix}} E_x^{\text{HF,SR}}(\omega) + a_{\text{mix}} E_x^{\text{HF,LR}}(\omega) + (1 - a_{\text{mix}}) E_x^{\text{PBE,SR}}(\omega) \\ & + E_x^{\text{PBE,LR}}(\omega) - a_{\text{mix}} E_x^{\text{PBE,LR}}(\omega) \end{aligned} \quad (7.60)$$

where ω is an adjustable parameter governing the extent of short-range interactions. For the exchange-mixing parameter value $a_{\text{mix}} = 0.25$ and $\omega = 0$ (7.60) is equal to the exchange part of the PBE0 parameter-free functional. Numerical tests based on realistic ω values ($\omega \approx 0.15$) indicate that the HF and PBE long-range exchange contributions of this functional are rather small (just a few percent) and that these terms tend to cancel each other [394].

Thus, if we neglect them and work under the assumption that this approximation may be compensated by other terms in the functional, one obtains a screened Coulomb potential hybrid density functional of the form

$$E_{xc}^{\omega PBE} = a_{\text{mix}} E_x^{\text{HF,SR}}(\omega) + (1 - a_{\text{mix}}) E_x^{\text{PBE,SR}}(\omega) + E_x^{\text{PBE,LR}}(\omega) + E_c^{\text{PBE}} \quad (7.61)$$

where ω is an adjustable parameter governing the extent of short-range interactions. The hybrid functional (7.61) is equivalent to PBE0 for $\omega = 0$ and asymptotically reaches PBE for $\omega \rightarrow \infty$.

The short-range component of the HF exchange can be obtained by using the SR Coulomb potential when calculating the electron-repulsion integrals for the HF exchange energy:

$$(\mu\nu|\lambda\sigma)^{\text{SR}} = \int \int d\mathbf{r}_1 d\mathbf{r}_2 \varphi_\mu(\mathbf{r}_1) \varphi_\nu(\mathbf{r}_1) \frac{\text{erfc}(\omega r_{12})}{r_{12}} \varphi_\lambda(\mathbf{r}_2) \varphi_\sigma(\mathbf{r}_2) \quad (7.62)$$

over contracted Gaussian-type functions. For these calculations, the algorithm of Gill and Pople [402] was modified [394] so that the evaluation of integrals (7.62) is only slightly more time-consuming than the regular electron-repulsion integrals.

To calculate the screened Coulomb exchange PBE functional, the exchange model hole J_x^{PBE} of the PBE functional constructed in a simple analytical form by Ernzerhof and Perdew [403] is used. The model hole reproduces the exchange energy density of the PBE approximation for exchange and accurately describes the change in the exchange hole upon the formation of single bonds. In the HSE functional, this PBE exchange hole is screened by employing the short-range Coulomb potential from (7.59).

The PBE long-range exchange contribution is then defined as the difference of the exchange-hole-based PBE and the SR PBE exchange energy densities.

In the so-called revised HSE03 hybrid functional [395], the improvement was introduced in the calculation in the integration procedure of the PBE exchange hole. This modification made the calculations numerically more stable and ensures that the HSE03 hybrid functional for $\omega = 0$ is closer to the PBE0 hybrid. The HSE03 (denoted also as $E^{\omega\text{PBE}}$) functional was incorporated into the development version of the GAUSSIAN code [404]. It was demonstrated for molecular systems that the HSE03 hybrid functional delivers results (bond lengths, atomization energies, ionization potentials, electron affinities, enthalpies of formation, vibrational frequencies) that are comparable in accuracy to the nonempirical PBE0 hybrid functional [395, 397, 398].

The HSE03 hybrid functional was extended to periodic systems [395]. The calculations were made for 21 metallic, semiconducting, and insulating solids. The examined properties included lattice constants, bulk moduli, and bandgaps. The results obtained with HSE03 exhibit significantly smaller errors than pure DFT calculations.

The preliminary screening of the integrals is necessary to take advantage of the rapid decay of short-range exchange integrals for periodic systems [395]. Two different screening techniques are used. In the first technique (Schwarz screening), substituting the SR integrals in place of the $1/r$ integrals yields an upper bound of the form

$$|(\mu\nu|\lambda\sigma)_{\text{SR}}| \leq \sqrt{(\mu\nu|\mu\nu)_{\text{SR}}} \sqrt{(\lambda\sigma|\lambda\sigma)_{\text{SR}}} \quad (7.63)$$

The $(\mu\nu|\lambda\sigma)$ integrals are then evaluated for each batch of integrals and only batches with nonnegligible contributions are used in calculating the HF exchange. The SR screening integrals are evaluated by the same procedure as the SR exchange integrals.

The second—distance-based multipole screening technique—uses multipole moments introducing the following screening criterion:

$$T_n = \sum_{M \in \mu\nu} \sum_{M \in \lambda\sigma} C_{\mu\nu}^{\max} \frac{1}{r^{l+M_{\mu\nu}^{\text{low}}+M_{\lambda\sigma}^{\text{low}}}} C_{\lambda\sigma}^{\max} \quad (7.64)$$

where T_n is an estimate for the contribution of a shell quartet and M is a multipole in the multipole expansion of a given shell pair. M_{ij}^{low} are the lowest-order multipoles that can contribute to the integral, and $C_{ij}^{\max}$ are the maximum coefficients in each order of multipoles. Replacing the $1/r$ potential with the $\text{erfc}(\omega r)/r$ short-range potential yields

$$T_n^{\text{SR}} = \sum_{M \in \mu\nu} \sum_{M \in \lambda\sigma} C_{\mu\nu}^{\max} \frac{\text{erf}(\omega r^{l+M_{\mu\nu}^{\text{low}}+M_{\lambda\sigma}^{\text{low}}})}{r^{l+M_{\mu\nu}^{\text{low}}+M_{\lambda\sigma}^{\text{low}}}} \quad (7.65)$$

This provides a distance-based upper bound for the SR exchange contribution of a given shell quartet.

The implementation of periodic boundary conditions relies on evaluating all terms of the Hamiltonian in real space [366]. The HF exchange is evaluated using replicated density matrices. All interactions within a certain radius from a central reference cell are calculated and the rest are neglected. This so-called near-field exchange (NFX) method [399] allows calculation of the HF exchange in time, scaling linearly with system size. It works reasonably well for insulating solids since the corresponding density matrix elements decay rapidly. In systems with smaller bandgaps, however, the spatial extent of nonnegligible contributions to the exchange energy is large. This large extent results in a large number of significant interactions. To render the computation tractable, the truncation radius must be decreased. Thus, significant interactions are neglected that leads to errors in the total energy of the system and introduces instabilities into the self-consistent field procedure.

Screened Coulomb hybrid functionals do not need to rely on the decay of the density matrix to allow calculations in extended systems [395]. The SR HF exchange interactions decay rapidly and without noticeable dependence on the bandgap of the system. The screening techniques do not rely on any truncation radius and provide much better control over the accuracy of a given calculation. In addition, the thresholds can be set very tightly, without resulting in extremely long calculations.

A series of benchmark calculations [395] on three-dimensional silicon (6-21G basis was used; see Chap. 8) demonstrates the effectiveness of the screening techniques. The time per SCF cycle was studied given as a function of the distance up to which exchange interactions were included in the calculation. As this radius

grows, the number of replicated cells grows as $O(N^3)$. The PBE0 curve tracks this growth since regular HF exchange has a large spatial extent. The relatively small bandgap of silicon (1.9 eV in this calculation) is insufficient for density matrix elements to decay noticeably. HSE, on the other hand, only shows a modest increase in CPU time as the system becomes larger. Beyond 10 Å, the CPU time only increases due to the time spent on screening. The HSE calculation of the total energy converges very rapidly, and only cells up to 10 Å from the reference cell contribute to the exchange energy. PBE0, by comparison, converges significantly slower. Thus, HSE not only reduces the CPU time drastically but also decreases the memory requirements of a given calculation since fewer replicated density matrices need to be stored in memory. In practice, HSE calculations can be performed with the same amount of memory as pure DFT calculations, whereas traditional hybrid methods have larger memory demands. Given the fast decay of the SR HF exchange interactions and the high screening efficiency, the HSE hybrid functional was efficiently applied to a variety of three-dimensional solids. We mention only some of these applications: (1) 21 metallic, semiconducting, and insulating solids [395]; (2) semiconductor set of 40 solids, containing 13 group IIA–VI systems, 6 group IIB–VI systems, 17 group III–V systems, and 4 group IV systems [405]; (3) the zincblende and rocksalt phases of platinum nitride [406] and platinum monoxide [407]; (4) lattice defects and magnetic ordering in plutonium oxides PuO_2 and Pu_2O_3 [408]; (5) carbon nanotubes [409]; and (6) actinide oxides UO_2 , PuO_2 and Pu_2O_3 [410]. It was demonstrated that the screened Coulomb hybrid density-functional HSE not only reduces the amounts of memory and CPU time needed, when compared to its parent functional PBE0, but it is also at least as accurate as the latter for structural, optical, and magnetic properties of solids. The PBE0 functional and other hybrid functionals are transferred from molecules to solids. The possibility of such a transfer we discuss in the next section.

7.2.4 Are Molecular Exchange-Correlation Functionals Transferable to Crystals?

The question in the title of this subsection arises due to the well-known fact that the properties of crystals are quite often different from those of molecular systems. The difference is particularly evident for ionic and semi-ionic solids, in which the long-range electrostatic forces provide a strong localizing field for the electronic states that are not present in molecules. In this situation, the shortcomings of standard LDA and GGA functionals, linked to the missing electronic self-interaction, are likely to be most severe [359]. This explains why the electronic-structure calculations in molecular quantum chemistry and solid-state physics were for a long time developing along two independent lines. While in the molecular quantum chemistry the wavefunction-based approaches (HF and post-HF) in the LCAO approximation were mainly used, in solid-state physics, DFT-based methods with plane wave (PW)

basis were popular. These two standard approaches were for a long time poorly transferable between the two fields [359]: early DFT functionals underperform post-HF techniques in reproducing the known properties of small molecules, while the extension of accurate post-HF methods to solid-state systems is difficult or has prohibitive computational expense.

The formulation of hybrid HF/DFT exchange-correlation functionals and their extension to periodic systems changed the situation; the combined HF–DFT approach has adequate accuracy for most needs in both quantum chemistry of molecules and solids, retaining a tractable computational cost and even allowing the system-size linear scaling. One appealing feature of this approach is that it can readily exploit the progress and tools available to the quantum chemists for calculating the HF exchange, as it was demonstrated in Sects. 7.2.2 and 7.2.3.

For molecules, the first hybrid functionals have been coded into GAUSSIAN94 in the MO LCAO approximation traditional for molecules. The DFT PW computer codes, existing for solids, can be modified to include HF method and hybrid exchange-correlation functionals [411]. However, the practical realization of HF method was made in LCAO approximation. The application of hybrid functionals to crystalline compounds (described under periodic boundary conditions (PBC)) was not possible until the late 1990s, when they were coded in CRYSTAL98 [412]. Numerous solid-state studies have been performed with molecular hybrid functionals, providing valuable experience on their accuracy and applicability. In the review article [359], the results are summarized of publications in which hybrid exchange functionals have been applied under PBC to represent crystalline solids. The list of later publications can be found on the site <http://www.crystal.unito.it>. The next step in the HF/DFT extension to solids was made by Scuseria and coworkers who coded the HF/DFT method with PBC in GAUSSIAN03 code [102] and included a linear-scaling hybrid exchange-correlation HSE functional.

The extension of HF–DFT methods to the crystalline solids encounters difficulties [359]. In molecular chemistry, very accurate thermochemical and structural data exist for a selection of simple species. These data have been effectively used to define representative sets against which to measure the results of calculations. The availability of these representative sets has enabled the *empirical* derivation of hybrid DFT functionals for molecules (e.g., B3LYP and B3PW functionals). Comparison to experiment in the solid state is often indirect: most reliable experimental results on crystalline solids are not directly related to the equilibrium structure, energy, and electronic density (as for molecules) but to the response of the solid to a perturbation, for instance, to elastic distortions or to external electromagnetic fields. As an additional complexity, some fundamental electronic properties of solids cannot be measured directly; bandgaps, for instance, can be readily calculated as edge-to-edge differences between specific filled and unfilled bands, but they cannot be measured directly. What experiments furnish are absorption edges and activation energies corresponding to processes that are often speculative. As another example, magnetic coupling constants can be neither measured nor calculated directly. Their extraction from calculations requires a mapping onto a phenomenological model of some sort, which by its very nature is inexact, while comparisons are made with

indirect quantities such as disorder-transition temperatures, which in turn have to be expressed in terms of the phenomenological model.

The second difficulty is the lack for solids of a reference theoretical method. Post-HF techniques in molecular quantum chemistry can yield results with a controlled degree of accuracy. In the absence of experimental data, the results obtained with different DFT functionals could be compared against those calculated with the reference computational technique. Recent developments in wavefunction methods for solid-state systems (Chap. 5), GW perturbation theory [413], and quantum Monte Carlo (QMC) [414] are promising for future work, but at present, they still suffer from a limited applicability.

In most solids, HF/DFT calculations with the CRYSTAL code [21] the B3LYP hybrid functional was used with the standard molecular formulation (with the mixing parameter $a_{\text{mix}} = 0.2$) and its results graded against a set of other Hamiltonians (HF, LDA, PWGGA, PBE). In some calculations of oxides, the different mixing parameter values were used [415–418]. These studies point to the need specific formulations of the hybrid functionals for solids, in particular systematic investigations on the effect of changing the mixing parameter. Such a systematic investigation on the effect of changing the mixing parameter from 0% to 100% was performed [359] for perovskite-structured transition-metal oxides AMO_3 (including ferroelectric materials BaTiO_3 and KNbO_3), rocksalt-structured oxides and fluorides, and open-shell defects in these matrices. All these systems share the fact that standard DFT calculations, in either LDA or GGA formulations, fail to reproduce with sufficient accuracy the correct electronic ground state and/or the structural and electronic properties of the material. Several observables have been examined (structural parameters, elastic constants and bulk moduli, phonon spectra, bandgaps, thermochemical data, point defects and surfaces, magnetic ordering). We refer the reader to the review article [359] for comments on each observable separately. The details of the LCAO basis and an auxiliary Gaussians for exchange-correlation calculation choice are given in [359]. The truncation thresholds and BZ summation parameters are also given, ensuring convergence of the total energies to within 0.1 meV.

As an example of observable calculations, we show in Table 7.2 some results obtained in [359] for structural properties (lattice constants and bulk moduli) of cubic perovskites. The first line of the table gives the exchange-correlation functional type. For the HF–DFT hybrid functional, both the standard molecular B3LYP functional and the BLYP exchange-correlation functional with a fraction a_{mix} of HF exchange (the numerical values of a_{mix} are given in the first line of Table 7.2) were used. For comparison, the available experimental data are given in the last column of this table. The following trends can be observed from the results given in Table 7.2. The lattice constant a increases systematically on increasing the mixing parameter a_{mix} and has a variation of approximately 3% in the series $0 < a_{\text{mix}} < 1$. The bulk modulus also increases with increasing a_{mix} , with a change for most materials of about 80% between $a_{\text{mix}} = 0$ and $a_{\text{mix}} = 1$. Increasing the percentage of the HF exchange in the functional, therefore, makes the structure more

Table 7.2 Equilibrium lattice parameter a (Å) and bulk modulus B (GPa) for cubic perovskites, as a function of a_{mix} parameter ($a_{\text{mix}} = 0.2, 0.4, 0.6, 0.8, 1.0$) in the DFT and hybrid B3LYP functional [359]

Solid		LDA	PW	BLYP	B3LYP	0.2	0.4	0.6	0.8	1.0	HF	Expt
CaTiO ₃	a	3.817	3.884	3.921	3.885	3.890	3.863	3.840	3.820	3.802	3.870	3.84
	B	213.8	187.2	175.8	194.6	193.0	208.9	223.2	236.5	248.5	218.0	
SrTiO ₃	a	3.888	3.960	4.001	3.959	3.965	3.935	3.909	3.887	3.867	3.937	3.90
	B	207.7	176.8	163.3	185.0	183.2	201.1	217.2	232.0	245.6	212.3	179
BaTiO ₃	a	3.953	4.024	4.072	4.033	4.039	4.011	3.987	3.966	3.947	4.020	4.01
	B	204.7	177.8	162.5	181.6	179.8	195.4	209.7	222.9	235.0	203.9	195
CaZrO ₃	a	4.084	4.149	4.186	4.155	4.160	4.137	4.117	4.098	4.081	4.150	4.02
	B	187.8	167.4	157.9	170.1	168.9	178.9	188.1	196.7	205.0	181.4	
SrZrO ₃	a	4.133	4.203	4.244	4.208	4.214	4.187	4.164	4.143	4.124	4.197	4.15
	B	179.4	157.3	147.5	161.4	160.1	171.7	182.0	191.9	201.1	176.1	
BaZrO ₃	a	4.167	4.235	4.282	4.249	4.255	4.232	4.212	4.193	4.175	4.250	4.19
	B	189.3	166.0	154.6	166.9	165.5	175.4	184.8	193.5	201.7	176.5	
NaNbO ₃	a	3.960	4.018	4.051	4.008	4.013	3.980	3.951	3.927	3.905	3.962	3.94
	B	203.7	178.0	168.3	188.2	186.6	205.4	222.9	238.7	235.1	226.7	
KNbO ₃	a	3.996	4.063	4.103	4.057	4.063	4.028	3.998	3.972	3.949	4.013	4.01
	B	197.4	172.1	158.9	182.5	181.0	200.5	218.8	235.6	251.0	221.5	
KTaO ₃	a	3.938	3.992	4.018	3.978	3.982	3.951	3.923	3.900	3.881	3.941	
	B	144.7	146.4	155.4	156.6	156.8	164.8	176.0	187.7	208.5	189.8	

compact and harder, and one may expect this feature to influence the behavior of the material toward structural distortions.

The lattice constant and bulk modulus are the ground-state properties defined by the total energy and its derivatives. The measured bandgap is defined by the excitation energies, and its calculation includes the eigenvalues corresponding to the bottom of the conduction band. Nevertheless, recent calculations with hybrid functionals show that the observed bandgaps are reliably reproduced in a wide variety of materials. As an example, we give in Table 7.3 the results of B3LYP LCAO bandgap calculations [419] in comparison with the experimental data.

To establish the reliability of the hybrid functional, the different types of materials have been studied: semiconductors (diamond and GaAs), semi-ionic oxides (ZnO, Al₂O₃, TiO₂), sulfides (FeS₂, ZnS), an ionic oxide MgO and the transition-metal oxides (MnO, NiO). For each system, the AO basis sets were developed and full structural optimization of the cell and internal coordinates was performed [419]. Typically, the optimized structural parameters are within $\pm 2\%$ of the experimental values. The bandgaps were determined from the band structure of the optimized system as the difference in the converged eigenvalues. As is seen from Table 7.3, even the molecular version of the B3LYP exchange correlation functional is capable of reproducing bandgaps for a wide variety of materials in good agreement with the experimental data (the latter even measured under well-controlled conditions are reliable to about 5% [419]). This agreement is at least as good as that obtained with more sophisticated correlated calculations or perturbation theories.

Table 7.3 A comparison of observed bandgaps with those calculated using the B3LYP functional for a wide range of materials (all values are given in eV) [419]

Material	Expt	B3LYP
Diamond	5.5	5.8
GaAs	1.4	1.5
ZnO	3.4	3.2
Al ₂ O ₃	9.0	8.5
Cr ₂ O ₃	3.3	3.4
MgO	7.8	7.3
MnO	3.6	3.8
NiO	3.8	3.9
TiO ₂	3.0	3.4
FeS ₂	1.0	2.0
ZnS	3.7	3.5

The latter studies confirmed the efficiency of HF/DFT approach for solids and also use of the HSE hybrid functional. In [405], a set of 40 semiconductors was chosen based on the following criteria: all considered systems were both closed shell and of simple or binary composition; the majority of them have simple zincblende or rocksalt structures, but also several systems with wurtzite structure were included. In addition, the availability of experimental data for lattice constants (and to a lesser extent bandgaps) was an important factor (the references to the experimental data can be found in [405]). These criteria led to the semiconductor/40 (SC/40) set of 40 solids containing 13 group IIA–VI systems, 6 group IIB–VI systems, 17 group III–V systems, and 4 group IV systems.

Table 7.4 contains a full list of all compounds and the calculated lattice constants and bandgaps. Based on the results of previous calculation with the HSE screened hybrid functional [395], the short-range–long-range splitting parameter was chosen as system independent and equal to 0.15, and the PBE0 functional mixing parameter was taken to be 0.25. The results in Table 7.4 are given for the LSDA, PBE, meta-GGA TPSS (Tao–Perdew–Staroverov–Scuseria[348]), and HSE hybrid functionals. All calculations employed the PBC option of the GAUSSIAN03 code, and total energies are accurate to 10^{-6} a.u. All basis sets used are modified molecular Gaussian basis sets (all diffuse basis functions with exponents below 0.12 were removed). The modification of the atomic basis sets for solids is discussed in Chap. 8 in more detail. For 31 of 40 systems, the inclusion of relativistic effects in the pseudopotential was examined. In Chap. 8, we discuss relativistic pseudopotentials in more detail. Table 7.4 gives in comparison with the experimental data the calculated lattice constants and bandgaps for 40 semiconductors (with optical bandgaps ranging from 0.2 to 7.2 eV). The comparison of results is given for three nonhybrid (LSDA, PBE, and TPSS) functionals and hybrid HSE functional. Table 7.5 contains the error statistics for predicting lattice constants a (in Å) and bandgaps (in eV).

As is seen from Table 7.4 LSDA underestimates lattice constants in nearly all cases, while PBE and TPSS always overestimate them. The screened hybrid functional HSE reduces the overestimation of PBE (on which it is based) drastically,

Table 7.4 Lattice constants (Å) and bandgaps (eV) for the set of 40 simple and binary semiconductors [405]

Solid	Lattice constants					Bandgaps				
	LSDA	PBE	TPSS	HSE	Expt.	LSDA	PBE	TPSS	HSE	Expt.
C	3.537	3.579	3.579	3.553	3.567	4.23	4.17	4.21	5.49	5.48
Si	5.410	5.479	5.466	5.444	5.430	0.59	0.75	0.82	1.28	1.17
Ge	5.634	5.776	5.744	5.701	5.658	0.00	0.00	0.00	0.56	0.74
SiC	4.355	4.404	4.394	4.372	4.358	1.40	1.46	1.42	2.39	2.42
BN	3.584	3.629	3.629	3.603	3.616	4.45	4.51	4.52	5.98	6.22
BP	4.509	4.567	4.566	4.543	4.538	1.31	1.41	1.45	2.16	2.40
BAs	4.750	4.829	4.821	4.794	4.777	1.16	1.27	1.29	1.92	1.46
BSb	5.201	5.291	5.280	5.251	n/a	0.80	0.88	0.81	1.37	n/a
AlN	(a) 3.112	3.153	3.147	3.127	3.111	4.9	4.95	5.01	6.45	6.13
	(c) 4.974	5.045	5.028	5.000	4.981					
AlP	5.436	5.508	5.497	5.472	5.463	1.60	1.83	1.90	2.52	2.51
AlAs	5.639	5.733	5.713	5.691	5.661	1.40	1.62	1.71	2.24	2.23
AlSb	6.079	6.188	6.172	6.146	6.136	1.29	1.40	1.63	1.99	1.68
GaN	(a) 3.167	3.233	3.224	3.198	3.189	2.09	1.70	1.73	3.21	3.50
	(c) 5.165	5.272	5.244	5.204	5.185					
β – GaN	4.476	4.569	4.552	4.518	4.523	1.93	1.55	1.56	3.03	3.30
GaP	5.418	5.534	5.522	5.484	5.451	1.59	1.71	1.98	2.47	2.35
GaAs	5.626	5.771	5.745	5.705	5.648	0.43	0.19	0.52	1.21	1.52
GaSb	6.043	6.208	6.183	6.140	6.096	0.09	0.00	0.08	0.72	0.73
InN	(a) 3.523	3.599	3.589	3.555	3.537	0.02	0.01	0.00	0.71	0.69
	(c) 5.684	5.807	5.765	5.729	5.704					
InP	5.839	5.970	5.961	5.909	5.869	0.83	0.68	0.90	1.64	1.42
InAs	6.038	6.195	6.170	6.120	6.058	0.00	0.00	0.00	0.39	0.41
InSb	6.430	6.608	6.585	6.535	6.479	0.00	0.00	0.00	0.29	0.23
ZnS	5.319	5.467	5.465	5.432	5.409	2.25	2.16	2.39	3.42	3.66
ZnSe	5.588	5.751	5.736	5.707	5.668	1.21	1.19	1.48	2.32	2.70
ZnTe	6.017	6.195	6.174	6.150	6.089	1.28	1.14	1.45	2.19	2.38
CdS	5.776	5.934	5.944	5.896	5.818	1.01	1.11	1.34	2.14	2.55
CdSe	6.025	6.210	6.195	6.152	6.052	0.34	0.48	0.73	1.39	1.90
CdTe	6.422	6.626	6.610	6.568	6.480	0.61	0.62	0.88	1.52	1.92
MgO	4.178	4.268	4.247	4.218	4.207	4.92	4.34	4.56	6.50	7.22
MgS	5.618	5.721	5.719	5.681	5.622	3.54	3.57	3.88	4.78	5.4
MgSe	5.417	5.532	5.520	5.499	5.40	1.70	1.76	2.07	2.62	2.47
MgTe	6.381	6.517	6.517	6.478	6.42	2.74	2.68	3.12	3.74	3.6
CaS	5.572	5.715	5.710	5.698	5.689	2.16	2.56	2.69	3.59	n/a
CaSe	5.799	5.962	5.955	5.946	5.916	1.74	2.11	2.23	3.02	n/a
CaTe	6.209	6.387	6.386	6.381	6.348	1.25	1.60	1.72	2.37	n/a
SrS	5.926	6.066	6.052	6.037	5.99	2.27	2.68	2.79	3.59	n/a
SrSe	6.151	6.306	6.290	6.282	6.234	1.89	2.26	2.37	3.09	n/a
SrTe	6.543	6.714	6.703	6.701	6.64	1.51	1.89	2.00	2.57	n/a
BaS	6.303	6.436	6.433	6.413	6.389	2.05	2.44	2.61	3.28	3.88
BaSe	6.517	6.671	6.659	6.649	6.595	1.76	2.12	2.26	2.87	3.58
BaTe	6.897	7.062	7.062	7.051	7.007	1.49	1.87	2.01	2.50	3.08

a—sphalerite structure, c—wurtzite structure

Table 7.5 Lattice constant a (in Å) and bandgap (in eV) error statistics for the set of 40 simple and binary semiconductors [405]

		LSDA	PBE	TPSS	HSE
Mean error	a	−0.046	0.076	0.063	0.035
	bandgap	−1.14	−1.13	−0.98	−0.17
Mean absolute error	a	0.047	0.076	0.063	0.037
	bandgap	1.14	1.13	0.98	0.26
Root-mean-square error	a	0.058	0.084	0.071	0.044
	bandgap	1.24	1.25	1.12	0.34
Maximum positive deviation	a	0.017	0.158	0.143	0.100
	bandgap	...	...	...	0.32
Maximum negative deviation	a	0.139	...	...	−0.014
	bandgap	−2.30	−2.88	−2.66	−0.72

leading to the best predictions overall. The 20% accuracy improvement of HSE over LSDA is noteworthy since LSDA is the most widely used method for lattice optimizations in solids. In addition, the overestimation of lattice constants by using the pseudopotentials (instead of all-electron calculations) is partly responsible for the observed errors with HSE. It is possible to expect that all-electron calculations yield even better results with HSE, while the underestimation exhibited by LSDA would only be exaggerated. Bandgaps calculated with all three nonhybrid density functionals are severely underestimated (mean absolute errors are about 1 eV; see Table 7.5), in extreme cases such as MgO, by as much as 2.88 eV. In addition, several small-bandgap systems (Ge, GaSb, InN, InAs, and InSb) are predicted to be quasimetallic. All bandgaps correspond to lattices optimized with the respective functional. The HSE hybrid functional yields a drastically reduced mean absolute error of only 0.26 eV and predicts even small-bandgap systems correctly. The HSE errors for bandgaps are comparable to those obtained with the GW approximation [420]. However, these calculations do not include any excitonic or quasiparticle effects. While these effects are small for some systems, they can be nonnegligible for others. Some systems in the SC/40 test set exhibit significant spin-orbit coupling effects that can split the bandgap by 1 eV, for example, ZnTe. For these systems, the comparison is made to the weighted average of the split experimental bandgap, but a better description of the systems is highly desirable. As follows from [405], the computational effort involved in HSE calculations presents only a modest increase (a factor of less than 2) over pure DFT calculations giving a vast improvement in accuracy.

Concluding the discussion of hybrid functionals, we stress that the HSE functional is universally applicable and does not contain any system-dependent parameter. It yields excellent results, in molecules and solids, for many different properties. In contrast to other methods, HSE can be employed for both structural and electronic properties; HSE provides a unique and powerful alternative for the study of large complex systems, such as chemisorption at surfaces and three-dimensional impurities in semiconductors. These fields of HSE functional applications await future study.

In the next subsection, we consider two orbital-dependent exchange-correlation functionals used for solids with the strong electron correlation. These functionals are used mainly with non-LCAO (PW, LMTO) basis and, from this point of view, are not quantum-chemical approaches. Therefore, we discuss them only briefly.

7.2.5 *Density-Functional Methods for Strongly Correlated Systems: SIC-DFT and DFT+U Approaches*

DFT (LDA, GGA approximations) have a great predictive power for solids only as long as one is treating electronic states extended over the whole system, so that electrons can be considered completely delocalized [142]. In the case of $3d$ states in transition-metal atoms and $4f$ states in rare-earth atoms and their compounds, the metal-atom electrons partially preserve their atomic-like (localized) nature. The Coulomb correlations between localized electrons are strong, so that DFT results in many cases are in disagreement with experiment. A well-known example of such a disagreement is represented by some insulating transition-metal oxides, which LDA predicts to be metallic. The DFT methods are in serious trouble for the strongly correlated electrons as these methods describe noninteracting electrons moving in an effective self-consistent mean field. For the strongly correlated molecular systems, post-HF methods in the LCAO approximation are traditionally applied (see Chap. 5). In solids with strong correlations, approaches based on LDA (GGA) approximations are applied as a starting point, and additional terms intended to treat strong Coulomb correlations between electrons are introduced. As a rule, the LCAO approximation is not used in these approaches. More traditional for solid-state physics, localized muffin tin orbitals (LMTO) or augmented plane waves (APW) are popular in the calculations of strongly correlated systems. Various methods have been developed to extend the DFT approach to the strongly correlated systems. The best suited for strongly correlated systems is the so-called GW approximation, which is formally the first term in the perturbation expansion of the self-energy operator in powers of the screened Coulomb interaction (we return to the Coulomb-screening problem later). The reader can find the detailed description of GW method in the review article by Aryasetiawan [421] and other publications. The GW approximation is computationally very heavy and some simpler methods were proposed. Two of these methods (self-interaction-corrected (SIC) DFT and DFT + U) are briefly discussed in this subsection.

The HF operator for a system of N electrons includes Coulomb $\hat{J}_j \psi_i(\mathbf{x}_1) = \int \frac{|\psi_i(\mathbf{x}_2)|^2}{|\mathbf{r}_2 - \mathbf{r}_1|} d\mathbf{x}_2 \psi_i(\mathbf{x}_1)$ and exchange $\hat{K}_j \psi_i(\mathbf{x}_1) = \int \frac{\psi_j^*(\mathbf{x}_2) \psi_i(\mathbf{x}_2)}{|\mathbf{r}_2 - \mathbf{r}_1|} d\mathbf{x}_2 \psi_j(\mathbf{x}_1)$ operators (here, $\psi_i(\mathbf{x})$ are spin-orbitals and $\mathbf{x} = \mathbf{r}, \sigma$ —the space $\mathbf{r}$ and spin σ coordinates). From the definitions of these operators, it follows that $\hat{J}_i \psi_i = \hat{K}_i \psi_i$. Without this identity the HF operator, would have been orbital-dependent $\hat{F} = \hat{H} + \sum_{j \neq i}^N (\hat{J}_j - \hat{K}_j)$, that is, we would have different HF operators for different orbitals.

By including the $i = j$ term, we obtain the same HF operator for all orbitals and allow the electron to interact with itself, in the Coulomb part and also in the exchange part. But these two self-interaction terms cancel. The HF approximation uses the exact expression of the exchange energy, but omits the correlation energy, and the resulting effective potential is nonlocal (it depends on the electron-density matrix $\rho(\mathbf{r}, \mathbf{r}')$). The DFT (LDA, GGA approaches) uses an approximate local form of the exchange-correlation energy and the Kohn–Sham effective potential is local (depends on the electron density $\rho(\mathbf{r}, \mathbf{r}) = \rho(\mathbf{r})$). In particular, the LDA is exact for a completely uniform system of noninteracting particles, and thus is self-interaction-free in this limit. In other versions of DFT, the approximate exchange-correlation energy functionals are used so that the self-interaction terms may not cancel. The self-interaction-corrected (SIC) DFT functionals must fulfill the equations, which describe their values in the limit of a single-electron system (hydrogen atom, for example) with density $\rho_\sigma(\mathbf{r})$, where σ may be α , $\int \rho_\alpha(\mathbf{r}) = 1$, and $\rho_\beta(\mathbf{r}) = 0$ [426]. The first equation

$$E_J[\rho] + E_X[\rho_\alpha, 0] = 0 \quad (7.66)$$

expresses that a single electron does not interact with itself, *that is*, the self-repulsion energy (Hartree energy) $E_J[\rho]$ is canceled by the self-exchange energy covered by the exchange functional $E_X[\rho]$. The second equation

$$E_c[\rho_\sigma, 0] = 0 \quad (7.67)$$

clarifies that a single electron does not possess any correlation energy (self-correlation is zero). The next two equations

$$v_J([\rho]; \mathbf{r}) + v_x^{\sigma}([\rho_\sigma, 0]; \mathbf{r}) = \text{const} \quad (7.68)$$

$$v_c^{\sigma}([\rho_\sigma, 0]; \mathbf{r}) = 0 \quad (7.69)$$

make sure that the single electron moves under the influence of the external potential $v(\mathbf{r})$ rather than the Coulomb potential v_J , the exchange potential v_x , or the correlation potential v_c . An approximate exchange-correlation functional may violate all or some of the Eqs. (7.66)–(7.69) and, therefore, has to be corrected. The common LDAs, GGAs, or Meta-GGAs have a remaining self-interaction error in their exchange part [422]. This self-interaction error is particularly critical for localized one-electron states in molecules and crystals. The delocalized electrons move fast, thus experiencing mainly the LDA (LSDA) mean-field potential; this is why LDA methods are so fruitful for metals. The localized electrons reside on each atomic site for so long that the surroundings must respond to their presence [423]. Therefore, the LDA theory problems are the most severe in systems where the electrons tend to be localized and strongly interacting (strongly correlated systems). As was already noted, the well-known examples of such systems are the

crystalline transition-metal oxides (with localized d -electron states) and rare-earth elements and compounds (with localized f -electrons). These systems exhibit phenomena associated with strong correlation effects (metal–insulator transitions, high temperature superconductivity, *etc.*). The already discussed hybrid DFT methods are most popular both in molecules and solids. The hybrid exchange-correlation functionals include HF exchange with some mixing coefficient and in this way, partly compensate the self-interaction error. Other possibilities of DFT extension to the strongly correlated systems are known: the self-interaction-corrected (SIC) DFT method by Perdew–Zunger [340] (PZ-SIC approach) and the LDA+U method by Anisimov–Zaanen–Anderson [144]. The SIC-LSDA and LDA+U methods are described in many publications and applied to different molecules and solids. We refer the reader to reviews [424–427].

Let the many-electron system consist of $N = N_\alpha + N_\beta$ electrons, where N_α and N_β are the number of electrons with spin α and spin β , respectively. The total density of electrons with spin σ is a sum of orbital densities $\rho_{i\sigma}(\mathbf{r}) = |\psi_{i\sigma}(\mathbf{r})|^2$. The total density of the N -electron system is $\rho(\mathbf{r}) = \sum_{\sigma} \sum_{i=1}^{N_\sigma} \rho_{i\sigma}(\mathbf{r})$. In the KS method, the energy of a many-electron system is expressed as

$$E^{\text{KS}}[\rho_\alpha, \rho_\beta] = \sum_{\sigma=\alpha,\beta} \sum_{i=1}^{N_\sigma} \langle \psi_{i\sigma} | -\frac{1}{2} \Delta | \psi_{i\sigma} \rangle + \int \rho(\mathbf{r}) v(\mathbf{r}) d\mathbf{r} + J[\rho] + E_{\text{xc}}[\rho_\alpha, \rho_\beta] \quad (7.70)$$

The first two terms in (7.70) are the kinetic energy of a system of noninteracting electrons and the interaction between the electron density $\rho(\mathbf{r})$ and external potential $v(\mathbf{r})$. The Hartree energy $J[\rho] = \frac{1}{2} \int \int \frac{\rho(\mathbf{r})\rho(\mathbf{r}')}{|\mathbf{r}-\mathbf{r}'|} d\mathbf{r} d\mathbf{r}'$ is the Coulomb interaction of an electron density with itself, E_{xc} is the exchange-correlation density-functional. The SIC-corrected density functional

$$E^{\text{SIC KS}} = E^{\text{KS}} - \sum_{\sigma=\alpha,\beta} \sum_{i=1}^{N_\sigma} (J[\rho_{i\sigma}] + E_{\text{xc}}[\rho_{i\sigma}, 0]) = E^{\text{KS}} + E^{\text{SIC}} \quad (7.71)$$

includes the self-interaction correction E^{SIC} for all occupied spin-orbitals, which eliminates all spurious self-interaction terms orbital by orbital. In the SIC-DFT, we have $E_{\text{c}}[\rho_\alpha, 0] = 0$ and $E_{\text{x}}[\rho_\alpha, 0] = -E_{\text{J}}[\rho]$, that is, an approximate exchange-correlation functional fulfills the exact conditions (7.67)–(7.68). The energy of equation (7.71) must be made stationary with regard to a mixing of occupied with occupied and occupied with virtual orbitals, which is accomplished by solving self-consistent KS equations for the SIC-DFT method. The SIC method gives significant improvements over the LSDA (SGGA) results [424], but there are also significant difficulties in applying the method. The SIC exchange-correlation potential becomes orbital dependent, and since the KS orbitals thereby are not solutions to the exact same Hamiltonian, one cannot in general be sure that the orbitals become

orthogonal. Due to the mixing of occupied orbitals in the SCF-SIC-DFT procedure, the energy functional is no longer invariant with regard to unitary transformations of the orbitals. To circumvent these problems, the optimized potential method was suggested [142, 329] allowing the local single-particle potential in the scheme that is both self-interaction-free and orbital independent to be found. The simplest approximate implementation of the SIC-DFT method in molecular codes is the SIC correction applied after a self-consistent KS calculation is done [428]. The references to other SIC-DFT method applications for molecules can be found in [429], where the SIC-DFT method was implemented self-consistently using a direct minimization approach. This approach was applied to calculate ionization potentials and electron affinities of atoms and small molecules [430]. It was concluded that this method works for molecules worse than for atoms; in particular, it significantly overcorrects the one-electron energy for the highest-occupied MO.

In condensed matter studies, the SIC-DFT calculations have been extensively used. A review of solid-state SIC-DFT techniques can be found in [424, 431, 432]. The well-known most serious failure of LSDA is an underestimation of energy gaps for semiconductors and insulators and the suppression of magnetic ordering for antiferromagnetic insulators. For transition-metal monoxide insulators with the sodium chloride structure (MnO, CoO, FeO, and NiO), the relative positions of transition-metal d bands and oxygen p bands are important to clarify whether they are Mott–Hubbard insulators or charge-transfer insulators. In Mott–Hubbard insulators, the occupied bands of transition-metal atoms appear at higher energy than the occupied p bands of oxygen atoms, while the relative positions are reversed in charge-transfer insulators. The lowest-unoccupied band is, in both cases, transition-metal d states. In the LSDA, the transition-metal d bands appear at higher energy than oxygen p bands, and therefore, they were considered as Mott–Hubbard-type materials. Such LSDA results do not agree with those by experiments and with the cluster calculations including correlation effects by the configuration interaction (CI) method. It was shown that the SIC removes unphysical self-interaction for occupied orbitals and decreases their energies [424, 433]. As in the case of molecules, the application of the SIC-LSDA to solids has severe problems. Since the SIC-LSDA energy functional is not invariant under the unitary transformation of the occupied orbitals, one can construct many solutions in the SIC-LSDA. If one chooses delocalized Bloch orbitals, the orbital charge densities vanish in the infinite-volume limit so that the SIC energy is exactly zero for such orbitals. But the localized Wannier orbitals constructed from Bloch orbitals have finite SIC energies. In many calculations for solids, the SIC was adapted to the localized orbitals, which are selected under some physical assumption. The criterion to choose these orbitals was carefully examined in [433], trying both solutions with localized and extended oxygen $2p$ orbitals. In solutions of types 1 (LSDA) and 2, all valence-state orbitals were extended or localized, respectively. In the solution of type 3, the transition-metal d orbitals were localized and the oxygen p orbitals were Bloch-type functions from the SIC potentials. In Table 7.6 are given bandgaps and magnetic moments of transition-metal monoxides for all the three types of SIC-LDA solution. The LDA+U results are discussed later. The type-1 solution is just the LSD result where

Table 7.6 Bandgaps and magnetic moments of transition-metal monoxides in SIC-LSDA, [433] and LSDA+U [425] calculations

Compound	Bandgap (eV)					Magnetic moment (μ_B)				
	Type 1	Type 2	Type 3	LSD	Expt.	Type 1	Type 2	Type 3	LSD	Expt.
	(LSD)	2	3	+U		(LSD)	2	3	+U	
MnO	1.1	6.5	3.4	3.5	3.6–3.8	4.5	4.7	4.7	1.67	4.79,4.58
FeO	0.0	6.1	3.4	3.2	2.4	3.2	3.7	3.6	3.62	3.32
CoO	0.0	5.3	2.7	3.2	2.4	2.0	2.7	2.6	2.63	3.35,3.38
NiO	0.0	5.6	2.8	3.1	4.0,4.3	0.7	1.7	1.5	1.59	1.77,1.64,1.93

all orbitals are extended, narrow *d*-bands appear at higher energy than the oxygen *p*-bands for all compounds. The bandgap of MnO is about 30% of the experimental value, there is no gap for other compounds. For the type 2 solution the transition-metal orbitals are more localized than those of oxygen *p* orbitals so that the SIC potentials are larger in transition-metal *d* orbitals and the energies of *d* orbitals are pulled down significantly. The *d*- and *p*-bands become strongly hybridized, in good agreement with the observed results. As is seen from Table 7.6, the energy gaps are overestimated but the magnetic moments are well estimated. In type-3 solutions the transition-metal *d* orbitals are localized and the oxygen *p* orbitals are Bloch-type functions free from the SIC potential, so that the *p* orbitals energies do not shift from the position of the LSDA results. On the contrary, the transition-metal *d* orbitals energies are pulled down below those of the oxygen *p* orbitals. Therefore, the highest-occupied band has the character of the oxygen *p*-band and the lowest-unoccupied band keeps mainly a character of the transition-metal *d* orbitals. Then, the transition-metal monoxides are the charge-transfer type. As is seen from Table 7.6 the SIC-LDA values of the bandgaps and magnetic moments are in good agreement with the experiment. Unfortunately, the hybridization of *p*- and *d*-bands for occupied states, which appeared in the type-2 solution, is not reproduced in the type-3 solution. At the same time the type-2 solution overestimates the bandgaps. It was cleared up [424] that this overestimation is due to the overestimate in LSD-SIC the Coulomb repulsion *U* of localized *d*-electron states in the solid (the SIC splits the occupied and unoccupied *d*-bands by the Coulomb repulsion *U* or slightly less than that). In condensed systems, the electron–electron Coulomb interaction is screened and the Coulomb repulsion should be much reduced. The “bare” (HF) value of the Coulomb interaction parameter *U* is 15–20 eV, while the screening in a solid to a much smaller value 8 eV or less [424]. This means that the SIC-LSDA functional form should be reformulated to include this screening. This is confirmed by investigations of *f*-electron bands in rare-earth element compounds [423]. The unscreened nature of Coulomb interaction is a serious problem of the Hartree–Fock approximation also—due to the neglect of screening, the HF energy gap values are a factor of 2–3 larger than the experimental values. A combination of the LDA and HF-type approximation called the LDA+*U* method was proposed [144]. The DFT+*U* solution can be obtained either at the LDA or GGA levels,

giving rise to what have been called the LDA+U and the GGA+U formulations, respectively. In this approach the contribution of the interaction to U is added to the LDA energy. Instead of the energy-dependent interaction the averaged static Coulomb interaction between localized orbitals is used. This approach can be viewed as a way of connecting the theory of strongly correlated systems, which is based on such models, with the *ab initio* electronic-structure calculation methods like the HF method [142]. In contrast to the GW approximation, where the screened Coulomb interaction is used in the form of a nonlocal energy-dependent operator, in the DFT+U method a set of site-centered atomic-type orbitals is introduced and the Coulomb interaction is present only between electrons on such orbitals. This can be called the “orbital-restricted” solution because the DFT-potential is the same for all orbitals (for example, for all five 3*d* orbitals of a transition-metal ion). The DFT+U method can reproduce the splitting of *d*- (or *f*-) bands into occupied lower and unoccupied upper bands, which was the main problem of LDA. This leads to the possibility of investigating the influence of correlation effects on structural properties, such as Jahn–Teller distortions. The orbital dependence of the DFT+U potential allows one to treat orbital and charge ordering in transition-metal compounds, which is very important for modern materials with anomalous magnetic and electronic properties.

In the LDA+U method electrons are separated into two subsystems: localized *d*- or *f*-electrons for which Coulomb *d*–*d* (*f*–*f*) interaction is taken into account by a term $\frac{1}{2}U \sum_{i \neq j} n_i n_j$ (n_i are *d* or *f* orbital occupancies) as in a mean-field (HF) approximation and delocalized *s*, *p*-electrons that could be described by using an orbital-independent one-electron LDA potential.

In the LDA+U method, the total Coulomb-interaction energy expression $E = UN(N-1)/2$ ($N = \sum_i n_i$) is subtracted from the LDA total energy and the orbital-dependent Coulomb-interaction energy is added:

$$E^{\text{LDA}+U} = E^{\text{LDA}} - UN(N-1)/2 + \frac{1}{2}U \sum_{i \neq j} n_i n_j \quad (7.72)$$

The orbital energies ε are derivatives of (7.72) with respect to the orbital occupations

$$\varepsilon_i = \frac{\partial E}{\partial n_i} = \varepsilon_{\text{LDA}} + U\left(\frac{1}{2} - n_i\right) \quad (7.73)$$

This simple formula shifts the LDA orbital energy by $-U/2$ for occupied orbitals ($n_i = 1$) and by $+U/2$ for unoccupied orbitals ($n_i = 0$). A similar formula is found for the orbital-dependent potential ($V_i(\mathbf{r}) = \frac{\delta E[\rho]}{\delta \rho_i(\mathbf{r})}$) where a variation is taken not on the total charge density $\rho(\mathbf{r})$ but on the charge density of a particular *i*th orbital $\rho_i(\mathbf{r})$:

$$V_i(\mathbf{r}) = V_{\text{LDA}}(\mathbf{r}) + U\left(\frac{1}{2} - n_i\right) \quad (7.74)$$

Such an approach introduces, in fact, the self-interaction correction for these orbitals. Therefore, SIC-DFT and DFT+U methods give close results in many cases.

The LDA+U orbital-dependent potential (7.74) gives the energy separation between the upper valence and lower conduction bands equal to the Coulomb parameter U , thus reproducing qualitatively the correct physics for Mott–Hubbard insulators. To construct a calculation in the LDA+U scheme, one needs to define an orbital basis set and to take into account properly the direct and exchange Coulomb interactions inside a partially filled d -(f -) electron subsystem [425]. To realize the LDA+U method, one needs the identification of regions in a space where the atomic characteristics of the electronic states have largely survived (“atomic spheres”). The most straightforward would be to use an atomic-orbital-type basis set such as LMTO [434].

As is seen from Table 7.6, the SIC-LSDA (type-3) and LSDA+U calculations give close results both for bandgaps and magnetic moments in transition-metal crystalline oxides. In both cases, the agreement with the experiment appears to be essentially better than in pure DFT LSDA calculations.

The deficiency of the DFT+U method is the necessity to define explicitly the set of localized orbitals for interacting electrons. While for rare-earth and transition-metal ions, the good approximation is to use atomic-type f or d orbitals and LMTO basis, for more extended systems like, for example, semiconductors, some more complicated Wannier-type orbitals are needed. Furthermore, the DFT+U method does not necessarily provide a reliable way of treating the U term, while, in a sense, all the important effects of strong correlation are defined by this term. Another problem of this method is that the estimate of U may depend on the choice of the basis [435]. Different choices of local orbitals such as the LMTO and LCAO give different U because the definition of the orbital becomes ambiguous whenever there is strong hybridization. In this situation, the U value fitted to experimental data can also be used. Recently, [436] the DFT+U method was implemented in the computer code VASP [437], which uses the pseudopotential description for core electrons (see Chap. 8) and plane waves as the basis in the Bloch-functions calculations. Use of this modified code allows the systematic DFT+U study of correlation effects in different solids. In particular, application of DFT+U method for transition-metal sulfides yielded improved predictions for volume, magnetic moment, exchange splitting, and bandgap [436]. In these calculations, the dependence of results on the U parameter is studied. It was shown that the observed width of the semiconducting gap is reached at $U=5$ eV in the LDA+U method and $U=3$ eV in the GGA+U method. The comparative DFT study with B3LYP (LCAO basis) and GGA+U (PW basis) of electronic-structure and magnetic coupling in FeSbO₄ crystal [438] allows the differences due to the different choice of exchange-correlation functional and basis to be estimated. In Table 7.7, we give the electronic bandgap values obtained in [438].

These results correspond to the experimentally found antiferromagnetic ordering of Fe ions in two dimensions. Such an ordering is correctly reproduced giving for the B3LYP functional the magnetic coupling constant value -21 K (experimental value is -25 K). From experimental studies, FeSbO₄ is known to be a charge-transfer

Table 7.7 Electronic bandgap values (in eV) in FeSbO₄ crystal, obtained for the antiferromagnetic solutions using different methods^a [438]

LCAO	Bandgap	Plane Waves	Bandgap
GGA(BLYP)	0.2	GGA(PW91)	0.2
B3LYP	3.0	GGA+U ($U_{\text{eff}} = 4 \text{ eV}$)	1.6
HF	12.8	GGA+U ($U_{\text{eff}} = 9 \text{ eV}$)	1.7

^a Experimental value is estimated as being greater than 0.75 eV (see explanations to this table in the text)

semiconductor (with an O2 p -Fe3 d bandgap), with an activation energy of 0.75 eV for n -type conduction. This value represents a lower limit for the bandgap, as is the energy required to excite electrons from the donor levels to the conduction band. In DFT+U calculations, the parameter U_{eff} is defined as the difference $U-J$ (J is a parameter representing the screened exchange energy, being almost constant at 1 eV). It was concluded [438] that the bandgap and the relative positions of the bands are affected in similar ways by the inclusion of 20% Hartree–Fock exchange and by the GGA+U correction with $U_{\text{eff}} = 4 \text{ eV}$. In particular, the occupied Fe-3 d levels shift down in the valence-band region for both methods, in comparison with the GGA solutions. However, increasing the HF exchange up to 100% and using higher values of U_{eff} do not have equivalent effects on the band structure, due to the local character of the GGA+U correction.

As a main conclusion of these calculations, we note the consistency between B3LYP and GGA+U results. *This means that LCAO calculations with hybrid functionals can play the same role in quantum chemistry of solids as DFT+U and SIC-DFT calculations in solid-state physics.*

Recent LDA+U calculations were made on different solids: ZnX ($X=\text{O}, \text{S}, \text{Se}, \text{Te}$) [439], NiO [440], and other transition-metal oxides (Cu₂O [441], ReO₂ [442], TiO₂ [443]). The results of these calculations confirm the efficiency of the DFT+U approach for strongly correlated systems. We hope that future LCAO calculations with the hybrid exchange-correlation functionals will discover the same efficiency.

This chapter concludes Part I (Theory) of our book. In Part II (Applications) we consider the applications in the quantum chemistry of solids of the theoretical methods described in Part I.

Part II

Applications

Chapter 8

Basis Sets and Pseudopotentials in Periodic LCAO Calculations

The following three approaches to the basis-set choice define three types of methods of electronic-structure calculations in crystals : atomic-sphere (AS) methods, plane-wave (PW) methods, and localized atomic-like orbitals (LCAO) methods. Each method has its advantages and disadvantages. The LCAO methods are more flexible as they allow both Hartree–Fock and Kohn–Sham equations to be solved, are applicable to the correlated wavefunction approaches (post-Hartree–Fock methods), and, in the Kohn–Sham theory based on hybrid exchange–correlation functionals, allow one to accurately describe electronic distributions both in the valence and the core region with a limited number of basis functions. In the periodic systems, the choice of the LCAO basis set is one of the critical points, due to the large variety of chemical bonding that can be found in a periodic system. The molecular basis sets of Gaussian-type functions can be considered as a starting point to generate atomic basis sets to be used in crystalline compounds. The adequacy of the starting molecular basis sets depends on the type of a crystalline compound. To improve a basis set, the more diffuse exponents (and contraction coefficients if necessary) are optimized. The effective core potentials (pseudopotentials) are based on the frozen-core approximation and serve to represent the potential generated by core electrons, also incorporating relativistic effects. The pseudopotentials used in modern periodic calculations (both relativistic and scalar-relativistic) are also discussed.

8.1 Basis Sets in the Electron-Structure Calculations of Crystals

8.1.1 *Plane Waves and Atomic-Like Basis Sets: Slater-Type Functions*

The choice of the basis set is of particular importance when treating periodic systems where a large variety of chemical bonding can be found. The following

three approaches to the basis-set choice define three types of methods of the electronic-structure calculations in crystals [10]: atomic-sphere (AS) methods, plane-wave (PW) methods, and localized atomic-like orbitals (LCAO) methods. Each method has its advantages and disadvantages.

The basic idea of AS methods is to divide the electronic-structure problem, providing efficient representation of atomic-like features that are rapidly varying near each nucleus and smoothly varying functions between atoms [10]. The smooth functions are augmented near each nucleus by solving the Schrödinger equation in the sphere at each energy and matching to the outer wave function. The resulting APW (augmented plane waves) or KKR (Kohn–Korringa–Rostoker) methods are powerful but require solution of nonlinear equations. The linear modifications of AS methods (LAPW, LMTO) use the familiar form of a secular equation involving a Hamiltonian and overlap matrix. The full-potential linear methods (FPLAPW) provide the most precise solutions of the Kohn–Sham equations.

The simpler PW methods are the most popular in the Kohn–Sham periodic-systems calculations. Plane waves are an orthonormal complete set; any function belonging to the class of continuous normalizable functions can be expanded with arbitrary precision in such a basis set. Using the Bloch theorem the single-electron wavefunction $\varphi_i(\mathbf{r})$ can be written as a product of a wavelike part and a cell-periodic part $\varphi_{i\mathbf{k}} = \exp(i\mathbf{k}\mathbf{r})u_i(\mathbf{r})$ (see Chap. 3). Due to its periodicity in a direct lattice, $u_i(\mathbf{r})$ can be expanded as a set of plane waves $u_i(\mathbf{r}) = \sum_{\mathbf{B}} C_{i\mathbf{B}} \exp(i\mathbf{B}\mathbf{r})$, where $\mathbf{B}$ is the reciprocal lattice vector. Thus, in the PW basis, the single-electron wavefunction can be written as a linear combination of plane waves:

$$\varphi_{i\mathbf{k}}(\mathbf{r}) = \sum_{\mathbf{B}} C_{i\mathbf{B}} \exp(i(\mathbf{k} + \mathbf{B})\mathbf{r}) \quad (8.1)$$

The number of basis functions used is controlled by the largest wavevector in the expansion (8.1). This is equivalent to imposing a cutoff on the kinetic energy as the kinetic energy of an electron with wavevector $(\mathbf{k} + \mathbf{B})$ is given by $\frac{|\mathbf{k} + \mathbf{B}|^2}{2}$. Thus, the size of the PW basis set is defined by the so-called cutoff energy, *that is*, the kinetic energy for the largest reciprocal lattice vector included in the PW basis. The Kohn–Sham equations take on a very simple form using plane waves [365]:

$$\left\{ \sum_{\mathbf{B}'} \left(\frac{1}{2} |\mathbf{k} + \mathbf{B}|^2 \delta_{\mathbf{B}\mathbf{B}'} + V_{\text{eN}}(\mathbf{B} - \mathbf{B}') + V_{\text{ee}}(\mathbf{B} - \mathbf{B}') + V_{\text{XC}}(\mathbf{B} - \mathbf{B}') \right) \right\} C_{i,\mathbf{k}+\mathbf{B}'} = C_{i,\mathbf{k}+\mathbf{B}} \varepsilon_{i\mathbf{k}} \quad (8.2)$$

where $V_{\text{eN}}(\mathbf{B} - \mathbf{B}')$, $V_{\text{ee}}(\mathbf{B} - \mathbf{B}')$, and $V_{\text{XC}}(\mathbf{B} - \mathbf{B}')$ are the Fourier transforms of the electronic–nuclei, electron–electron Coulomb, and exchange–correlation potentials.

The PW basis set is universal, in the sense that it does not depend on the positions of the atoms in the unit cell nor on their nature [444]. One does not have

to construct a new basis set for every atom in the periodic table nor modify them in different materials, as is the case with localized atomic-like functions, and the basis can be made better (and more expensive) or worse (and cheaper) by varying a single parameter—the number of plane waves defined by the cutoff energy value. This characteristic is particularly valuable in the molecular-dynamics calculations, where nuclear positions are constantly changing. It is relatively easy to compute forces on atoms. Finally, plane-wave calculations do not suffer from the basis-set superposition error (BSSE) considered later. In practice, one must use a finite set of plane waves, and this in fact means that well-localized core electrons cannot be described in this manner. One must either augment the basis set with additional functions (as in linear combination of augmented plane-wave scheme) or use pseudopotentials to describe the core states. Both AS and PW methods, developed in solid-state physics, are used to solve Kohn–Sham equations. We refer the reader to recently published books for the detailed description of these methods [9–11].

In the quantum chemistry of solids, the LCAO methods are preferable [444]. These methods are more flexible as they allow both Hartree–Fock and Kohn–Sham equations to be solved and are applicable in the correlated wavefunction approaches (post-Hartree–Fock methods, see Chap. 5) and in Kohn–Sham theory based on hybrid exchange–correlation functionals (see Chap. 7). In comparison with plane waves, the use of all-electron LCAO calculations allows us to describe accurately electronic distributions both in the valence and the core region with a limited number of basis functions. The local nature of the basis allows a treatment both of finite systems and of systems with periodic boundary conditions in one, two, or three dimensions. This has an advantage over plane-wave calculations of molecules, polymers, or surfaces that work by imposing artificial periodicity: the calculation must be done on, *for example*, a three-dimensional array of molecules with a sufficiently large distance between them (the molecule is placed at the center of a periodic supercell). LCAO total energies can be made very precise (*i.e.*, reliable to many places of decimals) since all integrals can be done analytically (in practice, this is only true for Hartree–Fock calculations; density-functional theory LCAO calculations require a numerical integration of the exchange–correlation potential that reduces the attainable precision). Having an “atomic-like” basis facilitates population analyses, the computation of properties such as projected densities of states, and “pre-SCF alteration of orbital occupation,” making the convergence of SCF calculations faster. As was already noted, the LCAO basis allows easy comparison of the results obtained for molecules and solids at the same precision level of calculations.

The molecular basis set atomic-like orbitals can be considered as a starting point to generate atomic basis sets to be used in crystalline compounds. Therefore, we begin with the molecular basis-set description.

In molecular quantum chemistry, two types of atomic-like basis sets are used: Slater-type orbitals (STO) and Gaussian-type orbitals (GTO). In fact, it is not really correct to call them “orbitals”. They are better described as basis-set functions, since they are Slater-type or Gaussian-type functions used to approximate the shapes of the orbitals defined as one-electron wavefunctions. Using the acronyms

accepted in solid-state theory, it would be possible to even call LCAO methods for crystals to “all-electron or full-potential linear combination of Slater (Gaussian)-type functions—FP LS(G)TF method” [444], compare with the acronym FP LAPW (full-potential linear combination of augmented plane waves).

The mathematical form of the normalized primitive Slater-type function (STF) in atom-centered polar coordinates is

$$\chi_{nlm}^{\text{STF}}(\mathbf{r}) = N_{nl}(\zeta)r^{n-1}\exp(-\zeta r)Y_{lm}(\theta, \varphi) = R_{nl}(r)Y_{lm}(\theta, \varphi) \quad (8.3)$$

where ζ is an orbital exponent, n is the principal quantum number, and $Y_{lm}(\theta, \varphi)$ are the spherical harmonics, depending on the angular-momentum quantum numbers l and m . STF have a number of features that make them attractive; see Sect. 6.1.1. We note the difference between Slater-type orbitals (8.3) and Slater orbitals introduced by Slater [200] and used in semiempirical LCAO methods; see Chap. 6. The radial part of the Slater orbitals $R_{nl}^*(r)$ depends on two parameters: the effective quantum number n^* and screening parameter constant s . The values of these parameters are given by the following rules:

1. n^* is assigned by the following table, in terms of the real principal quantum number n : for $n = 1, 2, 3, 4, 5, 6$ — $n^* = 1, 2, 3, 3.7, 4.0, 4.2$.
 2. For determining $(Z-s)$, the electrons are divided into the following groups, each having a different screening constant: $1s, 2s, 2p; 3s, 3p; 3d; 4s, 4p; 4d; 4f; 5s, 5p; 5d; etc.$ That is, the s and p of a given n are grouped together, but the d and f are separated. The shells are considered to be arranged from inside out in the order named.
 3. The screening constant s is formed, for any group of electrons, from the following contributions: (a) nothing from any shell outside the one considered and (b) an amount 0.35 from each other electron in the group considered (except in the $1s$ group, where 0.30 is used instead).
- (c) If the shell considered is an s, p shell, an amount 0.85 from each electron with total quantum number less by one and an amount 1.00 from each electron still further in, but if the shell is a d or f , an amount 1.00 from every electron inside it. As an example, we take the carbon atom C, $Z = 6$. Here, we have two $1s$ electrons, four $2s, 2p$ electrons. For the effective nuclear charge, $Z - s$, we have $1s : 6 - 0.30 = 5.70; 2s, p : 6 - 3(0.35) - 2(0.85) = 3.25$. As a second example, we take the iron atom Fe, $Z = 26$. There are two $1s$, eight ($2s, p$), eight ($3s, p$), six ($3d$), and two ($4s$). The effective nuclear charges are $1s : 26 - 0.30 = 25.70; 2s, p : 26 - 7(0.35) - 2(0.85) = 21.85; 3s, p : 26 - 7(0.35) - 8(0.85) - 2(1.00) = 14.75; 3d : 26 - 5(0.35) - 18(1.00) = 6.25; 4s : 26 - 1(0.35) - 14(0.85) - 10(1.00) = 3.75$. These simple rules give approximate Slater analytic atomic wavefunctions for all the atoms and ions.

The Slater orbitals can be written in the form (8.3) with the orbital exponent $\zeta = \frac{Z-s}{n^*}$ and $n = n^*$.

Table 8.1 HF–SCF occupied atomic orbitals for the ground state of a carbon atom given as linear combinations of s and p STOs [62]. The one-electron energies are given in a.u.

s		$1s : C$		$2s : C$		p		$2p : C$	
basis	ζ	ϵ	−11.32554	−0.70563	basis	ζ	ϵ	−0.43335	
$1s$	5.43599		0.93262	−0.20814	$2p$	0.98073		0.28241	
$1s$	9.48256		0.06931	−0.01071	$2p$	1.44361		0.54697	
$2s$	1.05749		0.00083	0.08099	$2p$	2.60051		0.23195	
$2s$	1.52427		−0.00176	0.75045	$2p$	6.51003		0.0.1025	
$2s$	2.68435		0.00559	0.33549					
$2s$	4.20096		0.00382	−0.14765					

The Slater-type functions (STF) with the radial part in the form (8.3) and integer n can be used as the basis functions in Hartree–Fock–Roothaan calculations of atomic wavefunctions. The radial dependence of the atomic orbitals is an expansion in the radial Slater-type basis functions φ_{lmp} whose indices are l , running over $s, p, d, f, \dots$ symmetries, and p counting serially over basis-set members for a given symmetry:

$$\varphi_{lmi} = \sum_p C_{lmp} R_{lp}(\mathbf{r}) Y_{lm}(\theta, \varphi) \quad (8.4)$$

The radial expansion is independent of m ; all electrons with a given l, i have the same radial dependence. The orbital angular dependence $Y_{lm}(\theta, \varphi)$ is a normalized spherical harmonic. The expansion coefficients C_{lmp} of the i th orbital, for the occupied atomic orbitals, are tabulated for elements with $Z=1-54$ in [62] and with $Z = 55 - 92$ in [445]. Relatively few primitive STOs are needed to closely approximate HF solutions of atoms (the latter are known as the contracted Slater-type orbitals). For example, six s -functions and four p -functions are enough to give seven-figure accuracy in total energy for the ground states of the first-row atoms. In Table 8.1, we give the results of Hartree–Fock–Roothaan carbon atom ground-state calculations. The one-electron energies ϵ of occupied $1s, 2s$, and $2p$ AOs and the corresponding primitive STFs orbital exponents ζ and coefficients C_{lmp} are shown. The STF basis set for the carbon atom can be denoted as $6s-6s4p$, meaning that the core $1s$ AO is represented by six s orbitals and the valence $2s$ and $2p$ orbitals are represented by six s - and four p - orbitals, respectively.

The Slater-type orbitals were the first to be used in the molecular quantum chemistry semiempirical calculations. Unfortunately, such functions are not suitable for fast calculations of multicenter integrals in *ab initio* calculations. Gaussian-type functions (GTFs) were introduced to remedy the difficulties. GTFs are used in basis sets in practically all modern codes for LCAO calculations of molecules. We know two exclusions from this rule—KS LCAO codes SIESTA (<http://www.uam.es/departamentos/ciencias/fismateriac/siesta/>) and ADF (<http://www.scm.com/Doc/Doc2006.01>). The SIESTA code uses a numerical AO basis set; the ADF code uses Slater-type basis-set orbitals (see Appendix C). In the next section we consider the GTF used in molecular quantum chemistry.

8.1.2 Molecular Basis Sets of Gaussian-Type Functions

A primitive Gaussian-type function can be written in a local Cartesian coordinate system in the form

$$\chi^{\text{GTF}} = x^l y^m z^n \exp(-\alpha r^2) \quad (8.5)$$

where α is the orbital exponent and the l, m, n are not quantum numbers but simply integral exponents of Cartesian coordinates. Gaussian primitives (8.5) can be factorized into their Cartesian components, *that is*, $\chi^{\text{GTF}} = \chi_x^{\text{GTF}} \chi_y^{\text{GTF}} \chi_z^{\text{GTF}}$, where each Cartesian component has the form (introducing an origin such that the Gaussian is located at position A),

$$\chi_x^{\text{GTF}} = (x - x_A) \exp(-\alpha(x - x_A)^2) \quad (8.6)$$

This simplifies considerably the calculation of integrals. If we write the exponential part of an STF, $\exp(-\alpha r)$ in Cartesian components, we get $\exp(-\alpha \sqrt{x^2 + y^2 + z^2})$ that is not so separable. Note that the absence of the STO pre-exponential factor r^{n-1} restricts single Gaussian primitives to approximating only $1s, 2p, 3d$, *etc.* orbitals and not, $2s, 3p, 4d$, *etc.* However, combinations of Gaussians are able to approximate correct nodal properties of atomic orbitals if the primitives are included with different signs. The sum of exponents of Cartesian coordinates $L = l + m + n$ is used analogously to the angular-momentum quantum number for atoms to mark Gaussian primitives as s -type ($L = 0$), p -type ($L = 1$), d -type ($L = 2$), f -type ($L = 3$), *etc.* From six $3d$ GTFs ($x^2, xy, xz, yz, y^2, z^2$), there are only five linearly independent and orthogonal atomic d orbitals being linear combinations of Cartesian Gaussians ($3z^2 - r^2, xz, yz, x^2 - y^2, xy$); the sixth combination $x^2 + y^2 + z^2 = r^2$ is Gaussian primitive of s -type. It is clear that the behavior of a Gaussian is qualitatively wrong both at the nuclei and in the long-distance limit for a Hamiltonian with point-charge nuclei and Coulomb interaction. From this point of view, STFs would be preferable.

In the so-called Pople basis sets, the basis functions are made to look more like Slater-type functions by representing each STF χ^{STF} as a linear combination of Gaussian primitives:

$$\chi^{\text{STF}} = \sum_{i=1}^N C_i \chi_i^{\text{GTF}} \quad (8.7)$$

where C_i is a fixed coefficient and N is the number of Gaussian primitives used to represent the Slater-type basis function. The sums (8.7) are known as the contracted Gaussian basis set. Linear combinations of Gaussian primitives allow the representation of the electron density close to the nucleus to be improved. Recall that STF has a cusp at the nucleus while GTF does not. By taking linear combinations of Gaussian primitives, the cusplike behavior is better reproduced.

The Gaussian basis set can also be used without any connection with the Slater-type orbitals: HF equation solutions for atoms are reached by Roothaan's expansion method with Gaussian-type functions as was done with STFs (see Sect. 8.1.1).

The details of both procedures—Gaussian expansion of Slater-type orbitals and atomic SCF calculations with Gaussian-type basis—are well known in molecular quantum chemistry [446]. It was found that GTF expansions require inclusion of more primitives than STF expansions for the same accuracy in the total and one-electron SCF energies for atoms. For example, in the case of the carbon atom, the inclusion of 10 *s*-type primitive GTFs and 6 *p*-type primitive GTFs is necessary (10*s* – 10*s*6*p*) to obtain only six-figure accuracy in the total energy (in the STF case, seven-figure accuracy was obtained for 6 and 4 STF *s*-type and *p*-type primitives, respectively).

In molecular quantum chemistry, Gaussian-type basis functions are expanded as a linear combination (contraction) of individually normalized Gaussian primitives $g_j(\mathbf{r})$ characterized by the same center and angular quantum numbers but with different exponents:

$$\chi_i(\mathbf{r}) = \sum_{j=1}^N d_j g_j(\mathbf{r}), \quad g_j(\mathbf{r}) = g(\mathbf{r}; \alpha, l, m) = N_{lm}(\alpha) r^l Y_{lm}(\theta, \phi) \exp(-\alpha_j r^2) \quad (8.8)$$

where N is the length of the contraction, the α_j are the contraction exponents, and the d_j are contraction coefficients. Gaussian primitives can be written in terms of real spherical harmonics including a normalization constant.

If accurate solutions for an atom are desired, they can be obtained to any desired accuracy in practice by expanding the “core” basis functions in a sufficiently large number of Gaussians to ensure their correct behavior. Furthermore, properties related to the behavior of the wavefunction near nuclei can often be predicted correctly, even without an accurately “cusped” wavefunction [447]. In most molecular applications, the asymptotic behavior of the density far from the nuclei is considered much more important than the nuclear cusp [444]. The molecular wavefunction for a bound state must fall off exponentially with distance, whenever the Hamiltonian contains Coulomb electrostatic interaction between particles. However, even though an STFs basis would, in principle, be capable of providing such a correct exponential decay, this occurs in practice only when the smallest exponent in the basis set is $\zeta_{\min} = \sqrt{2I_{\min}}$, where $I_{\min}$ is the first ionization potential. Such a restriction on the range of exponent values, while acceptable for atomic SCF calculations, is far too restrictive for molecular and solid-state work. Some of these formal limitations have thus turned out to be of relatively little importance in practice.

By proper choice of the N , α_j , and d_j in the contraction (8.8), the “contracted Gaussians” may be made to assume any functional form consistent with the primitive functions used. One may therefore choose the exponents of the primitives and the contraction coefficients so as to lead to basis functions with desired properties, such as reasonable cusplike behavior at the nucleus (*e.g.*, approximate Slater functions or HF atomic orbitals). Integrals involving such basis functions reduce to sums of integrals involving the Gaussian primitives. Even though many primitive integrals may need to be calculated for each basis-function integral, the basis-function integrals will be rapidly calculated provided the method of calculating

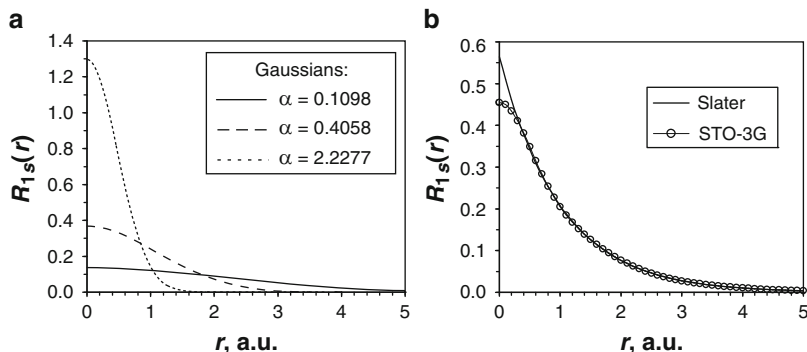


Fig. 8.1 1s orbitals, [444]: (a) Gaussian and (b) Slater and fitted STO-3G

primitive integrals is fast, and the number of orbital coefficients in the wavefunction will have been considerably reduced. The exponents and contraction coefficients are normally chosen on the basis of relatively cheap atomic SCF calculations so as to give basis functions suitable for describing exact Hartree–Fock atomic orbitals. An approximate atomic basis function, whose shape is suitable for physical and chemical reasons, is thus expanded in a set of primitive Gaussians, whose mathematical properties are attractive from a computational point of view. Note that the physical motivation for this procedure is that, while many primitive Gaussian functions may be required to provide an acceptable representation of an atomic orbital, the relative weights of many of these primitives are almost unchanged when the atoms are formed into molecules or crystals. The relative weights of the primitives can therefore be fixed from a previous calculation, and only the overall scale factor for this contracted Gaussian function need be determined in the extended calculation. It is clear that contraction will in general significantly reduce the number of basis functions.

For molecular basis sets of Gaussian-type functions (GTF), general acronyms and notations are used that are well known in molecular quantum chemistry.

A *Minimal basis sets* are constructed by using one Slater-type orbital basis function of each type occupied in the separated atoms that comprise a molecule. If at least one *p*-type, *d*-type, or *f*-type orbital is occupied in the atom, then the complete set (3 *p*-type, 5 *d*-type, 7 *f*-type) of functions must be included in the basis set. The simplest of these basis sets is that designated *STO-3G*, an acronym for *Slater-type-orbitals* simulated by 3 primitive Gaussians added together. The coefficients of the Gaussian functions are adjusted to give as good a fit as possible to the Slater orbitals. To illustrate this, let us consider a 1s Slater-type orbital radial part $\exp(-\zeta r)$ (for $\zeta = 1.0$, it is an exact hydrogen atom atomic orbital). A plot of this STO function is given in Fig. 8.1b, taken from [444]. A plot of Gaussian-type orbitals $\exp(-\zeta r^2)$ for different orbital exponents is shown in Fig. 8.1a. Note the cusp at the origin for the Slater-type orbital, while the Gaussian-type orbital has no cusp at the origin. In addition, the shape of the Gaussian-type orbital is different

due to the squared distance that appears in its exponent. In Fig. 8.1a are shown individually three 1s-Gaussian primitives with orbital exponents 0.1098, 0.4058, and 2.2277. When the Gaussian primitives are combined using the coefficients 0.4446, 0.5353, and 0.1543, a new STO-3G function is produced, which is shown in Fig. 8.1b. It is seen that the new basis function resembles the Slater-type orbital much more closely than any of the single Gaussian-type orbitals. The only slight variation is observed near the cusp. The new basis function, because it consists of Gaussian primitive functions, does not have a cusp. However, the overall shape even close to the nucleus is very much like the Slater-type orbital.

Only one best fit to a given type of Slater orbital is possible for a given number of Gaussian functions. Hence, all STO-3G basis sets for any row of the periodic table are the same, except for the exponents of the Gaussian functions. The exponents are expressed as scale factors, the squares of which are used as multipliers of the adjusted exponents in the original best-fit Gaussian functions. In this way, the ratios of exponents remain the same, while the effective exponent of each orbital can be varied,[444]. The STO-3G basis set and other minimal basis sets usually do reasonably well at reproducing geometries of only simple organic molecules. The minimal basis sets do not allow alteration of the basis orbitals in response to a changing molecular environment and therefore make comparison between charged and uncharged species unreliable. Anisotropic environments are another problem for minimal basis sets [444].

Because the core electrons of an atom are less affected by the chemical environment than the valence electrons, the core electrons can be treated with a minimal basis set, while the valence electrons are treated with a larger basis set. This is known as a *split-valence basis set*. In these bases, the AOs are split into two parts: an inner, compact orbital, and an outer, more diffuse one. The coefficients of these two kinds of orbitals can be varied independently during construction of the MOs. Thus, the size of the AO can be varied between the limits set by the inner and outer functions. Basis sets that similarly split the core orbitals are called double zeta, DZ (implying two different exponents), or triple zeta, TZ (implying three different exponents). For example, the 3-21G notation of split-valence basis set means that the core orbitals are represented by three Gaussians, whereas the inner and outer valence orbitals consist of two and one Gaussians, respectively. If we were to name bases consistently, of course, this one would be labeled STO-3-21G, but the STO is customarily omitted from all split-valence descriptors. Two other split-valence bases are the 6-31G and the 6-311G. Both have six Gaussian cores. The 6-311G is a triply split basis, with an inner orbital represented by three Gaussians, and middle and outer orbitals represented as single Gaussians. The triple split improves the description of the outer valence region.

Further improvement of the basis set is achieved including *polarization functions* in the basis set. For example, this is done by adding *d* orbitals to the basis of all atoms having no *d*-electrons. For typical organic compounds, these are not used in bond formation, as are the *d* orbitals of transition metals. They are used to allow a shift of the center of an orbital away from the position of the nucleus. For example, a *p* orbital on carbon can be polarized away from the nucleus by mixing

into it a d orbital of lower symmetry. One obvious place where this can improve results is in the modeling of small rings; compounds of second-row elements also are more accurately described by the inclusion of polarization. The presence of polarization functions is indicated in the Pople notation by appending an asterisk to the set designator. Thus, 3-21G* implies the previously described split-valence basis with polarization added. Typically, six d -functions (x^2 , y^2 , z^2 , xy , xz , and yz), equivalent to five d orbitals and one s , are used (for computational convenience). Most programs can also use five real d orbitals. An alternative description of this kind of basis is DZP: double zeta polarization. A second asterisk, as in the 6-31G** basis set, implies the addition of a set of p orbitals to each hydrogen to provide for their polarization. Again, an alternative notation exists: DZ2P(double zeta 2 polarization). An asterisk in parentheses signals that polarization functions are added only to second-row elements. Another alternative to the asterisk for specifying polarization functions is (d), placed after the G.

To provide more accurate descriptions of anions, or neutral molecules with unshared pairs, basis sets may be augmented with so-called *diffuse functions*. These are intended to improve the basis set at large distances from the nuclei, thus better describing the barely bound electrons of anions. Processes that involve changes in the number of unshared pairs, such as protonation, are better modeled if diffuse functions are included.

The augmentation takes the form of a single set of very diffuse (exponents from 0.1 to 0.01) s and p orbitals. The presence of diffuse functions is symbolized by the addition of a plus sign, +, to the basis set designator: 6-31+G. (Since these are s and p orbitals, the symbol goes before the G.)

Again, a second + implies diffuse functions added to hydrogens; however, little improvement in results is noted for this addition unless the system under investigation includes hydride ions.

All of the codes for molecular *ab initio* calculations offer at least one set of diffuse functions. Still more extensive basis sets exist and are described by more complicated notation.

Let us summarize the notations used for molecular GTO basis sets. Basis sets denoted by the general nomenclature N-M1G or N-M11G, where N and M are integers, are called Pople basis sets. The first, N-M1G, is a split-valence double-zeta basis set, while the second, N-M11G, is a split-valence triple-zeta basis set. The integers N and M in the basis set name give the number of Gaussian primitives used. For example, in the split-valence double-zeta basis set 6-31G for a carbon atom, the first number (N=6) represents the number of Gaussian primitives used to construct the core orbital basis function (the $1s$ function). The second two numbers (M=3 and 1) represent the valence orbitals, $2s$, $2s'$, $2p(3)$, and $2p'(3)$. The first number after the dash in the basis set name (3 in this case) indicates the number of Gaussian primitives used to construct the $2s$ and $2p(3)$ basis functions. The second number after the dash (1 in this case) gives the number of Gaussian primitives used to construct the $2s'$ and $2p'(3)$ basis functions. There are two common methods for designating that polarization functions are included in a basis set. The first method is to use * or ** after the Pople basis set name, for example, 6-31G*

Table 8.2 The basis sets and orbitals they include

Basis	AOs on C*	AOs on H
STO-3G	$1s, 2s, 2p_x, 2p_y, 2p_z$	$1s$
3-21G*	$1s, 2s, 2p, 3s, 3p$	$1s, 2s$
3-21+G*	$1s, 2s, 2p, 3s, 3p, 4s, 4p$	$1s, 2s$
6-31G	$1s, 2s, 2p, 3s, 3p$	$1s, 2s$
6-31G*	$1s, 2s, 2p, 3s, 3p, 3d$	$1s, 2s$
6-31G**	$1s, 2s, 2p, 3s, 3p, 3d$	$1s, 2s, 2p$
6-31+G*	$1s, 2s, 2p, 3s, 3p, 3d, 4s, 4p$	$1s, 2s$
6-311G*	$1s, 2s, 2p, 3s, 3p, 3d, 4s, 4p$	$1s, 2s, 3s$
6-11++G(2df, 2pd)	$1s, 2s, 2p, 3s, 3p, 3d, 4s, 4p, 4d, 4f$	$1s, 2s, 2p, 3s, 3p, 3d, 4s$

or 6-31G**. The single * means that one set of d -type polarization functions is added to each nonhydrogen atom in the molecule. The double ** means that one set of d -type polarization functions is added to nonhydrogens and one set of p -type polarization functions is added to hydrogens. The second method for including polarization functions in the basis-set designation is more general. It is indicated by the notation (ll,l2) following the Pople basis-set name, for example, 6-31G(d) or 6-31G(d, p). The first label indicates the polarization functions added to nonhydrogen atoms in the molecule. The notations 6-31G(d) and 631G(d, p) mean that one set of d -type polarization functions is added to all nonhydrogens. The notation 6-311(2df) means that two sets of d -type and one set of f -type polarization functions are added to nonhydrogens. The second label in the notation (ll,l2) indicates the polarization functions added to hydrogen atoms. The basis set 6-31G(d) has no polarization functions added to hydrogen, while the basis 6-31G(d, p) has one set of p -type polarization functions added to hydrogen atoms. The basis set 6-311G(2df, 2pd) has two sets of p -type and one set of d -type polarization functions added to hydrogen atoms. The use of diffuse functions in a Pople basis set is indicated by the notation + or ++. The + notation, as in 6-31+G(d), means that one set of sp -type diffuse basis functions is added to nonhydrogen atoms (4 diffuse basis functions per atom). The ++ notation, as in 6-31++G(d), means that one set of sp -type diffuse functions is added to each nonhydrogen atom and one s -type diffuse function is added to hydrogen atoms.

In Table 8.2, we give a list of basis sets of orbitals that are commonly used in modern MO calculations. The H and C atomic orbitals that are included are listed. The first set contains “Gaussian-like orbitals.” Outside of the STO-3G basis set, most Gaussian basis sets are “split-valence,” which means that they use different numbers of Gaussian functions to describe core and valence atomic orbitals. Thus, a 6-31G basis set uses 6 Gaussians for the core orbitals and two sets of Gaussians for the valence orbitals, one with 3 Gaussians and another with one. Adding more Gaussians allows more flexibility in the basis set so as to give a better approximation of the true orbitals. Therefore, although some of the basis sets incorporate the same AOs, the larger ones provide a much better description of them. For each basis set, polarization (*) and diffuse functions (+)4 can also be added, which add flexibility into the basis set.

Table 8.3 Correlation-consistent polarized valence X-zeta (XZ) basis sets

Basis	AOs on C	AOs on H
cc-pVDZ	1s, 2s, 2p, 3s, 3p, 3d	1s, 2s, 2p
cc-pVTZ	1s, 2s, 2p, 3s, 3p, 3d, 4s, 4p, 4d, 4f	1s, 2s, 2p, 3s, 3p, 3d
cc-pVQZ	1s, 2s, 2p, 3s, 3p, 3d, 4s, 4p, 4d, 4f, 5s, 5p, 5d, 5f, 5g	1s, 2s, 2p, 3s, 3p, 3d, 4s, 4p, 4d, 4f
cc-pV6Z	total of 7s, 6p, 5d, 4f, 3g, 2h, i	

Alternate basis sets that are commonly used are the Dunning correlation-consistent polarized valence X-zeta basis sets, denoted cc-pVXZ; see Table 8.3. Dunning pointed out that basis sets optimized at the Hartree–Fock level might not be ideal for correlated computations [448]. The “correlation-consistent” basis sets are optimized using correlated wavefunctions, and cc-pVXZ means a Dunning correlation-consistent, polarized valence, X-zeta basis; X=D,T,Q,5,6,7. In particular, the cc-pVDZ for C atom consists of $3s2p1d$, cc-pVTZ would be $4s3p2d1f$, and cc-pVQZ would be $5s4p3d2f1g$ (see Table 8.3). The advantage of these is that increasing basis-set size is systematic. In fact, if energies are calculated with the cc-pVDZ, cc-pVTZ, and cc-pVQZ basis sets, then there is an analytical function that can be used to extrapolate to cc-pVmZ (the complete basis-set limit). Unfortunately, cc-pVQZ calculations are not commonly doable. Moreover, cc-VXZ functions are more difficult to integrate than the Gaussian functions, and these calculations take longer even for comparably sized basis sets. Dunning basis sets already contain polarization functions, but they can be augmented with diffuse functions.

The EMSL (the environmental molecular sciences laboratory) [<http://www.emsl.pnl.gov/forms/basisform.html>] library supplies a wide selection of atomic basis sets optimized for molecules. This library allows extraction of Gaussian basis sets and any related effective core potentials (the effective core potentials are considered in the next sections), from the Molecular Science Research Center’s Basis Set Library. A user may request the basis set be formatted appropriately for a wide variety of popular molecular electronic-structure packages. In addition to the exponents and contraction coefficients that define the basis set, the user can obtain descriptive data that include the overall philosophy behind the basis literature citations, the angular-momentum composition of the basis, and many other pieces of information.

Molecular AO basis sets can formally be used in periodic LCAO calculations, but their adequacy must be carefully checked [21]. We discuss in the next section the modification of molecular basis sets to the study of crystals.

8.1.3 Molecular Basis-Set Adaptation for Periodic Systems

In the periodic systems the basis sets are chosen in such a way that they satisfy the Bloch theorem. Let a finite number m_A of contracted GTFs be attributed to the atom A with coordinate $\mathbf{r}_A$ in the reference unit cell. The same GTFs are then

formally associated with all translationally equivalent atoms in the crystal occupying positions $\mathbf{r}_A + \mathbf{a}_n$ ($\mathbf{a}_n$ is the direct lattice translation vector). For the crystal main region of N primitive unit cells, there are $N \sum_A m_A$ Gaussian-type Bloch functions (GTBF) constructed according to

$$\chi_{ki}(\mathbf{r}) = \frac{1}{\sqrt{N}} \sum_{\mathbf{a}_n} \exp(i\mathbf{k}\mathbf{a}_n) \chi_i(\mathbf{r} - \mathbf{r}_A - \mathbf{a}_n) \quad (8.9)$$

The total number M of GTBFs equals $M = \sum_A m_A$ where the summation is made over atoms of the reference cell. Thus, in solids, the basis-set functions are modulated over the infinite lattice: any attempt to use large uncontracted molecular or atomic basis sets, with very diffuse functions, can result in the wasting of computational resources [21]. Therefore, exponents and contraction coefficients in the molecular and periodic systems are generally rather different, and with some exceptions, such as molecular crystals and certain covalent solids, molecular basis sets are not directly transferable to the study of crystalline solids. As in the case of molecules, basis functions in solids are grouped into shells. In general, a shell contains all functions characterized by the same n and l quantum numbers (*e.g.*, all the different d -functions in a $3d$ shell); this allows the partitioning of the total charge density into “shell charge distributions” and is useful in the selection of bielectronic integrals and in the evaluation of long-range interactions. A feature of the contraction schemes originally used in the basis sets of the Pople type (and often useful in calculations with the CRYSTAL code [21]) is the additional grouping of basis functions with only the same principle quantum number into shells, *for example*, a $2sp$ shell, in which both $2s$ and $2p$ functions have the same set of exponents α_j but different contraction coefficients d_j . For STF, this is illustrated by Table 8.1. This procedure reduces the number of auxiliary functions to be calculated in the evaluation of electron integrals. Note that if the basis set is restricted to s , p , and d basis functions, only sp shells may be formed in this way. In certain circumstances, it may actually represent an important constraint on the form of the basis functions. For relatively small calculations where the time and storage limitations are not an important factor, some consideration should be given to describing the s and p functions with separate sets of exponents. Most standard molecular codes use what is known as a segmented contraction scheme, in which the transformation from the larger primitive set to the smaller contracted set is restricted in such a way that each Gaussian primitive $g_j(\mathbf{r})$ contributes to exactly one contracted GTF. In contrast, the general contraction scheme makes no such assumptions and allows each Gaussian primitive to contribute to several contracted GTFs. A considerable advantage of the general scheme is that the contracted GTFs reproduce exactly the desired combinations of primitive functions. For example, if an atomic SCF calculation is used to define the contraction coefficients in a general contraction, the resulting minimal basis will reproduce the SCF energy obtained in the primitive basis. This is not the case with segmented contractions. There are

other advantages with a general contraction: for example, it is possible to contract inner-shell orbitals to single functions with no error in the atomic energy, making calculations on heavy elements much easier. Another advantage is a conceptual one: using a general contraction, it is possible to perform calculations in which the one-particle space is a set of atomic orbitals, a true LCAO scheme, rather than being a segmented grouping of a somewhat arbitrary expansion basis. The MOs or COs can then be analyzed very simply, just as for the original qualitative MO LCAO or CO LCAO approach, but in terms of “exact AOs” rather than relatively crude approximations to them.

We describe here in more detail some computational aspects of GTFs use in the CRYSTAL code [21], following [444]. The important reason for the usefulness of a Gaussian basis set is embodied in the Gaussian product theorem (GPT), which in its simplest form states that the product of two primitive Gaussian functions with exponents α and β , located at centers $\mathbf{A}$ and $\mathbf{B}$, is itself a primitive Gaussian with exponent $\gamma = \alpha + \beta$, multiplied by a constant factor F and located at a point $\mathbf{C}$ along the line segment $\mathbf{A} - \mathbf{B}$, where $\mathbf{C} = \frac{\alpha\mathbf{A} + \beta\mathbf{B}}{\gamma}$ and $F = \exp\left(-\frac{\alpha\beta}{\gamma}(\mathbf{A} - \mathbf{B})^2\right)$.

The product of two polynomial GTF, of degree μ and ν and located at points $\mathbf{A}$ and $\mathbf{B}$, is therefore another polynomial GTF located at $\mathbf{C}$ of degree $\mu + \nu$ in x_C , y_C , and z_C , which can be expressed as a short expansion of one-center Gaussians:

$$\chi_{Ax}(x)\chi_{Bx}(x) = \sum_{i=0}^{\mu+\nu} C_i^{\mu+\nu} \varphi_{Ci}(x - x_C) \quad (8.10)$$

where $\varphi_{Ci}(x) = x^i \exp(-\alpha_p(x - x_c)^2)$ and $x_c = \frac{\alpha x_A + \beta x_B}{\alpha + \beta}$.

The product of two Gaussians that are functions of the coordinates of the same electron is referred to as an overlap distribution, and all the integrals that must be calculated involve at least one such overlap distribution. The most important consequence of the GPT is that all four-center two-electron integrals can be expressed in terms of two-center quantities. CRYSTAL code actually uses a common and more efficient approach for the evaluation of integrals over Gaussian basis functions, in which Hermite–Gaussian functions (HGFs) are used instead of the usual Cartesian Gaussians in the re-expansion (8.10). Hermite–Gaussians are defined as derivatives of an s -type Gaussian:

$$\Lambda(\xi) = H_i(\xi) \exp(-\alpha_p(x - x_p)^2) = (-1)^i \frac{d^i}{d\xi^i} \exp(-\xi^2) \quad (8.11)$$

where $H_i(\xi)$ is a polynomial of order i and $\xi = \alpha_p^{1/2}(x - x_p)$. The set of HGFs spans the same space as the expansion functions in (8.10), and as a consequence, they can be used for expanding the basis-function products:

$$\chi_{Ax}(x)\chi_{Bx}(x) = \sum_{i=0}^{l_A+l_B} C_i^{l_A+l_B} \Lambda_i(\xi) \quad (8.12)$$

where the expansion coefficients must now be redefined. Because of the natural relations between Hermite polynomials and Gaussians, the necessary two-center integrals can be evaluated with very high efficiency. Basis functions with higher quantum numbers can be generated through repeated differentiation of an s -type Gaussian. Even though the four-center bielectronic integrals can be written in terms of two-center quantities, the cost of evaluating them still scales nominally as N^4 , where N is the number of functions in the expansion. This scaling must be reduced in order to treat large systems. One way of doing this that is used in CRYSTAL is the method of *prescreening* where, rather than attempting to calculate the integrals more efficiently, one seeks, where possible, to avoid their evaluation altogether. The expression for an integral over primitive Gaussians can be formally written as

$$(ab|cd) = S_{ab}S_{cd}T_{abcd} \quad (8.13)$$

where S_{ab} is a radial overlap between functions χ_a and χ_b and T_{abcd} is a slowly varying angular factor. In many situations, the product $S_{ab}S_{cd}$ thus constitutes a good estimate of the magnitude of the integral whose product is used as an estimate in screening out small integrals. In order to estimate these overlaps quickly, a single, normalized s -type Gaussian called an *adjoined Gaussian* is associated with each shell, whose exponent α is the smallest of the exponents in the shell contraction. This function thus reproduces approximately the absolute value of the corresponding AOs at intermediate and long range. The adjoined Gaussian is used in fast algorithms for estimating overlaps on the basis of which integrals are either evaluated exactly, approximately, or not at all. The level of approximation is user-definable through a set of tolerances given in the input. Such algorithms, and a consideration of the crystalline symmetry, mean that the integral part of CRYSTAL code scales at between N and N^2 , depending on the size of the system. The most unpleasant scaling in this code is thus the SCF part that, since it involves diagonalization of the Fock matrix, scales as approximately N^3 . It requires a special consideration of the role of diffuse basis-set functions in crystalline systems. Very diffuse functions can yield numerical instabilities and risk of linear-dependent catastrophes [444]. Furthermore, due to the truncation criteria of the infinite sums, based on the overlap, decreasing the exponents of the primitive Gaussians the number of integrals to be calculated increases very rapidly. Too extended basis sets are not needed in periodic calculations because the complete basis-set limit is reached quicker than in molecular calculations. Furthermore, the risk of linear dependence problems increases. The choice of the AO basis set is a compromise between accuracy and costs. As the accuracy must be the main goal of *ab initio* calculations, the good-quality basis sets should always be used in spite of their computational cost to avoid producing meaningless numbers.

The choice of the basis set (BS) is one of the critical points, due to the large variety of chemical bonding that can be found in a periodic system. For example, carbon can be involved in covalent bonds (polyacetylene, diamond) as well as in strongly ionic situations (Be_2C , where the Mulliken charge of carbon is close to -4). Some general principles of the basis-set choice for periodic systems are

formulated [21, 444], and we briefly reproduce them here. Much experience gained in the molecular computational chemistry can be used in the selection of basis sets for studies of crystalline solids. However, the molecular quantum chemists do not, in general, optimize basis sets by varying the exponents or contraction coefficients to minimize the energy. Rather, there is a hierarchy of basis sets with perceived qualities, and for a difficult problem where accuracy is important, one would use a “good-quality” standard basis set from a library without modification. In crystalline systems by contrast, basis-set optimization is usually necessary, essentially for two reasons. First, there is a much larger variety of binding than in molecules, and basis sets are thus less transferable. Secondly, hierarchical libraries of basis sets comparable to those available for molecules do not really exist for solids. For certain types of compounds, such as molecular crystals or many covalent materials, the molecular sets can sometimes be used largely unmodified, but this has to be done carefully. However, for strongly ionic crystals and metals, the basis sets, particularly the valence states, need to be redefined completely. In essentially all cases, the core states may be described using the solutions of atomic calculations, as even in the presence of strong crystal fields, the core states are barely perturbed and may be described by the linear variation parameters in the SCF calculation.

Redefining basis sets in this way is obviously time consuming and even more obviously rather boring, and so over recent years, various workers involved with the CRYSTAL code have contributed to an effort to develop libraries of basis sets to be made available on the Internet. The URL of the official site is: www.crystal.unito.it/Basis~sets/Ptable.html. We recommend to the reader to use the information given on this site. The site shows a periodic table. Clicking on the symbol for the required element will reveal a text file containing various different basis sets that may have been used in different materials containing that element type. Accompanying each basis set is a list of authors, a list of materials where the set has been used, references to publications, and hints on optimization where relevant. This table is obviously not complete (in particular, lanthanides and actinides are not practically represented as the calculations with f -electrons are not included even in the CRYSTAL06 code). Additional information can be found on the site of Cambridge basis set library: www.tcm.phy.cam.ac.uk/~mdt26/crystal.html.

We follow [444] in discussion of optimization strategies for the basis sets given in the libraries mentioned and also the adaptation of molecular bases for various types of solids. First, a number of general principles are given that should be taken into account when choosing a basis set for a periodic system.

The *diffuse basis functions* are used in atoms and molecules to describe the tails of the wavefunction, which are poorly described by the long-range decay of the Gaussian function. In periodic systems, the cost of HF/DFT calculations can more essentially increase when the diffuse basis functions are included (in the silicon and diamond crystals, e.g., the number of bielectronic integrals, can increase by a factor of 10 simply by changing the exponent of the most diffuse single Gaussian from 0.168 to 0.078 (Si) and from 0.296 to 0.176 (C) [444]. Fortunately, in crystalline compounds in contrast to molecules, particular in nonmetallic systems, the large overlap between neighbors in all directions drastically reduces the contribution of

low-exponent Gaussians to the wavefunction. This has the consequence that a small “split-valence” basis set such as 6-21G is closer to the Hartree–Fock limit in crystals than in molecules.

The *number of primitives* is an important feature of the basis set. A typical basis set for all-electron calculations includes “core functions” with higher exponents and a relatively large number of primitives—these will have a large weight in the expansion of the core states. The “valence functions” with a large weight in the outer orbitals will have lower exponents and contractions of only a very few primitives. It is possible to get away with putting a lot of primitives in the core since core states have very little overlap with neighboring atoms. The use of many primitives in the valence shells would add significantly to the cost of a calculation, but in many cases, it is necessary.

There are several ways to improve a basis set [444]: (1) reoptimize the more diffuse exponents (and contraction coefficients if necessary); (2) decontract, *that is*, convert the more diffuse contractions into single Gaussian primitives; (3) convert *sp* functions into separate *s* and *p* functions; (4) add polarization functions if not already present; (5) add more primitives (watch out for linear dependence problems); and (6) use a better starting point for the basis set. Optimization in this sense means varying an appropriate subset of the basis-set parameters until the energy is minimized. In principle, this is a reasonably complex multidimensional minimization, but there are various standard shell scripts available. Two of them can be downloaded from the Internet sites: BILLY code www.tcm.phy.cam.ac.uk/~mdt26/downloads/billy.tar.gz and LoptCG code (www.crystal.unito.it/LoptCG/LoptCG.html).

The adequacy of the starting molecular basis sets depends on the type of crystalline compound.

To describe *covalent crystals*, the small molecular split-valence basis sets can be used with confidence and essentially without modification. It is enough to reoptimize the exponent of the most diffuse shell, which produces a slightly improved basis, while reducing the cost of the calculation. That said, 6-21G* is not really all that good, and a larger better basis set with more variation freedom is quite easy to make for these cases (see Web libraries).

For *fully ionic* crystals (like alkali halides, LiH or MgO) with an almost completely empty cation valence shell, it often proves convenient to use a basis set containing only “core” functions plus an additional *sp* shell with a relatively high exponent. It is usually difficult, and often impossible, to optimize the exponents of functions that only have appreciable weight in almost empty orbitals. Anions present a different problem. Reference to isolated ion solutions is possible only for halides, because in such cases, the ions are stable even at the Hartree–Fock level. For other anions, which are stabilized by the crystalline field, the basis set must be redesigned with reference to the crystalline environment. Consider, for example, the optimization of the oxygen basis set in Li₂O [444]. The difficulty is to allow the valence distribution to relax in the presence of two more electrons. We can begin from a standard STO-6G basis set, *that is*, six contracted primitive Gaussians for the 1*s* shell, and six more to describe the 2*sp* shell. First, two more Gaussians were

introduced into the $1s$ contraction, in order to improve the virial coefficient and total energy. The two outer Gaussians of the valence sp shell were then removed from the contraction and allowed to vary independently. The exponents of the two outer independent Gaussians and the coefficients of the four contracted ones were optimized in Li_2O . The best outer exponents of the ion were found to be 0.45 and 0.15 and are therefore considerably more diffuse than the neutral isolated atom, where the best exponents are 0.54 and 0.24. The rest of the oxygen valence shell is unchanged with respect to the atomic situation. The introduction of d functions in the oxygen basis set gives only a minor improvement in the energy, with a population of 0.02 electrons/atom/cell (d functions may be important in the calculation of certain properties, however). Thus, for anions, reoptimization of the most diffuse valence shells is mandatory when starting from a standard basis set.

The majority of crystals can be classified as *semi-ionic* (with chemical bonding being intermediate between covalent and purely ionic limits). For such crystals, the adequacy of selected basis sets must be carefully tested as is discussed in [444], for example, for semi-ionic compounds SiO_2 (quartz) and Al_2O_3 (corundum). The exponents of the outer shell for the two cations (Si and Al) used in molecular calculations prove to be too diffuse. For the Si atom in quartz, reoptimization in the bulk gives $\alpha = 0.15$ (instead of the molecular value 0.09). Corundum is more ionic than quartz, and in this case, it is better to eliminate the most diffuse valence shell of Al and to use two Gaussians of the inner valence shells as independent functions ($\alpha = 0.94$ and $\alpha = 0.3$, respectively).

For *metals*, very diffuse Gaussians are required to reproduce the nearly uniform density so that it was often stated that the plane waves are a more appropriate basis for these systems. It is generally impossible to optimize atomic-like basis set in Hartree–Fock calculations of metallic systems. However, Gaussian DFT studies indicate that GTFs are able to provide a reliable and efficient description of simple metallic systems (see, e.g., metallic lithium calculations [449]). Thus, the effects of basis set and Hamiltonian were separated.

UHF and hybrid DFT calculations for strongly correlated *transition-element magnetic compounds* require the reasonably good basis sets for the transition elements. These are not that widely available even to molecular quantum chemists since most of the effort in developing molecular GTF basis sets has been for first- and second-row atoms. One reason for this may be that molecules containing transition metal atoms tend to be very badly described at the Hartree–Fock level. Molecular bonds tend to have a fairly high degree of “covalency,” and the existence of partially occupied d states leads to a great many nearly degenerate levels and thus to a large “static correlation” (*i.e.*, the weight of the HF determinant in a CI expansion would be small, and a multideterminant treatment is more appropriate). Basis sets to describe the correlation using quantum chemistry correlated wavefunction techniques need to be much richer than those for systems well described at the HF level since they need to treat all of the unoccupied levels. It may seem surprising that single-determinant HF could be so successful in periodic crystalline magnetic insulators containing transition elements, but this is an important characteristic of these ionic materials. The highly symmetric environment and long-range Coulomb

forces tend to separate the orbitals into well-defined subsets with a significant gap between occupied and unoccupied states. Hence, the ground state of NiO, for example, is rather well described by a single determinant. In this sense, a strongly correlated magnetic insulator is in many ways a “simpler system” than many molecules. The success of UHF calculations in these materials (and also hybrid DFT schemes) is now well known. We consider some examples of such calculations in Chap. 9. Molecular GTF basis sets for transition elements have been reoptimized in the solid state and are available on the Torino and Cambridge Gaussian basis-set library Web sites referred to earlier.

In the final part of this section, we shall discuss a rather serious problem, associated with Gaussian basis sets—basis-set superposition error (BSSE). A common response to this problem is to ignore it since it will go away in the limit of a complete basis, but to achieve this limit, one needs calculations that are seldom performed. The problem of BSSE is a simple one: in a system comprising interacting fragments A and B, the fact that in practice the basis sets on A and B are incomplete means that the fragment energy of A will necessarily be improved by the basis functions on B, irrespective of whether there is any genuine binding interaction in the compound system or not. The improvement in the fragment energies will lower the energy of the combined system giving a spurious increase in the binding energy. It is often stated that BSSE is an effect that one needs to worry about only in calculations on very weakly interacting systems. This is not really true [444]. BSSE is an ever-present phenomenon, and accurate calculations should always include an investigation of BSSE. Examples of areas in which one should be particularly worried are the study of the binding energy of molecules adsorbed on surfaces (see, e.g., [450] for an interesting discussion) or the calculation of defect-formation energies.

The approach most commonly taken to estimate the effect of BSSE is the counterpoise correction of Boys [451]: the separated fragment energies are computed not in the individual fragment basis sets, but in the total basis set for the system including “ghost functions” for the fragment that is not present. These energies are then used to define a counterpoise-corrected (CPC) interaction energy, which by comparison with perturbation theory has been shown to converge to the BSSE-free correct value [452].

Linear dependencies of Gaussian-type orbital basis sets employed in the framework of the HF–SCF method for periodic structures, which occur when diffuse basis functions are included in a basis set in an uncontrolled manner, were investigated [453]. The basis sets constructed avoid numerical linear dependences and were optimized for a number of periodic structures. The numerical AO basis sets for solids were generated in [454] by confining atoms within spheres and smoothing the orbitals so that the first and second derivatives go to zero at the boundary. This forms small atomic-like basis sets that can be applied to solid-state problems and are efficient for treating large systems.

We considered the basis sets for all-electron calculations in which all the core electrons are involved explicitly. Both in molecular and solid-state quantum chemistry, the core states can be treated implicitly as creating an effective core potential

(pseudopotential). The pseudopotential approximation becomes the most efficient for crystalline compounds of heavy elements. Simultaneously, the relativistic effects on the electronic structure play an important role. In the next sections, we consider nonrelativistic and relativistic pseudopotentials used in modern LCAO calculations of periodic systems. The choice of the corresponding valence basis sets is also discussed.

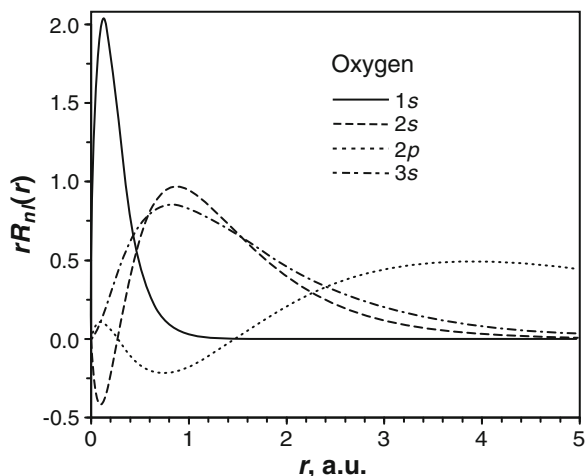
8.2 Nonrelativistic Effective Core Potentials and Valence Basis Sets

8.2.1 *Effective Core Potentials: Theoretical Grounds*

It is well established from chemical experience that most chemical properties of molecules and solids are determined by the valence electrons of the constituent atoms. The core states are weakly affected by changes in chemical bonding. The effect of core electrons is principally to shield the nuclear charges and to provide an effective potential for the valence electrons. The main reason for the limited role of the core electrons is the spatial separation of the core and valence shells that originates from the comparatively strong binding of the core electrons to the nucleus. This effect is illustrated in Fig. 8.2, (<http://www.physik.uni-frankfurt.de/~engel/ncpp.html>), where the radial orbitals of the oxygen atom are plotted. The spatial separation of the $1s$ core state from the valence $2s$, $2p$ states and unoccupied (excited) $3s$ state is seen. The HF eigenvalues of $1s$, $2s$, and $2p$ states (for the ground state of free oxygen atom) are -20.6687 a.u., -1.2443 a.u., and -0.6319 a.u., respectively [62], *that is*, the valence and core eigenvalues differ by an order of magnitude. The precise decomposition of electrons into core and valence becomes more difficult when the spatial and/or energetic separation between two shells breaks down. This is, for instance, the case for the $3d$ transition metal elements, for which the most weakly bound $4s$ state is not well separated from the $3d$ states and the latter are not well separated from $3s$, $3p$ states (e.g., in the case of Ti atom, HF one-electron energies are -0.2208 a.u. ($4s$), -0.4407 a.u. ($3d$), -1.7952 a.u. ($3p$), -2.8735 a.u. ($3s$) [62]). As a result, the overlap of the $3d$ orbitals (and even $3s$, $3p$ orbitals) with the orbitals from neighboring atoms is too large to be ignored. In this situation, large core and small-core effective potentials can be introduced; the former differs from the latter by exclusion of the $3s$, $3p$ electrons from the core.

The idea behind effective core potentials (ECPs), also called pseudopotentials (PPs), is to treat the core electrons as creating effective averaged potentials rather than actual particles. Effective core potentials are based on the frozen-core approximation and serve to represent the potential generated by core electrons, also incorporating relativistic effects. ECP application can introduce significant computational efficiencies as it allows formulation of a theoretical method for dealing only with the valence electrons while retaining the accuracy of all-electron

Fig. 8.2 Radial orbitals of oxygen atom in the ground state (<http://www.physik.uni-frankfurt.de/~engel/ncpp.html>)



methods. Fock, Veselow, and Petrashen were the first to formulate the approach for treating a subset of the electrons, such as the valence electrons, in the field of the remaining electrons. They considered the special case of atoms with two valence electrons outside a closed shell [96].

As we already noted, the pseudopotentials are essentially mandatory in plane-wave calculations of solids since the core orbitals have very sharp features in the region close to the nucleus and too many plane waves would be required to expand them if they were included. In atomic-like basis-set calculations, pseudopotentials are formally not mandatory and have different characteristics from those designed for plane waves since localized basis functions actually have necessary sharp features in the core region. Nevertheless, ECP methods are also used in LCAO calculations of molecules and solids since the difficulty of the standard LCAO methods rises rapidly with the number of electrons. If the CPU time in LCAO calculations was dominated by the integral calculation, PP introduction would not give very much since the number of integrals is controlled by more diffuse functions that overlap strongly with neighboring atoms. These diffuse functions are introduced mainly to describe the change of atomic valence states. However, the use of ECP will decrease the number of coefficients in the one-electron wavefunctions and might give significant savings in the SCF part. It is also quite easy to incorporate relativistic effects into pseudopotentials, which is increasingly important for heavy atoms. All-electron relativistic calculations are very expensive and in many cases are practically difficult.

The parameters and the underlying basis set of so-called energy-consistent ECPs can be adjusted in accordance with representative experimental data, not only for the ground state, but also for excited states, electron affinities, ionization potentials, and so on. Being of semiempirical origin, they can perform remarkably well for a given system, but their transferability to other environments can be poorer than that of shape-consistent ECPs. So-called shape-consistent ECPs (known in computational condensed matter as the norm-conserving ECPs) are rather easy

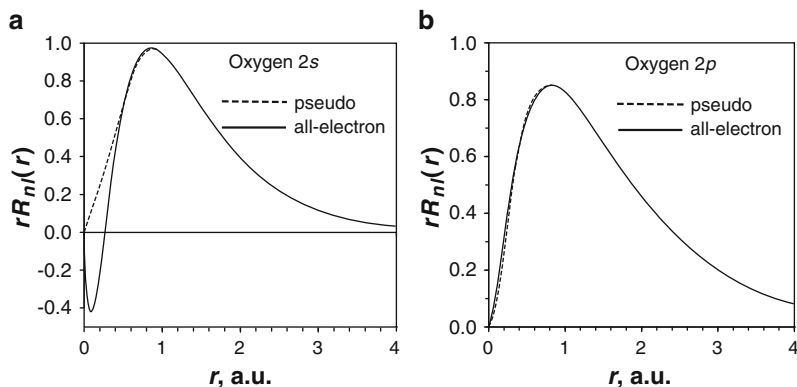


Fig. 8.3 Radial pseudo- versus all-electron orbitals of oxygen: (a) $2s$ (b) $2p$ (<http://www.physik.uni-frankfurt.de/~engel/ncpp.html>)

to derive and contain no adjustable parameters, *that is*, these are *ab initio* ECPs. The construction of shape-consistent ECPs for molecules is based on the original proposal of Christiansen et al. [455] where shape consistency was introduced. Simultaneously, norm-conserving ECP were introduced in computational condensed-matter physics by Hamann et al. [456]. This example demonstrates practically independent development of ECPs for molecules and crystals when for the same ECP property different terms are used. The work by Phillips and Kleinman (PK) [457] is an important step in the ECP applications for solids. PK developed the pseudopotential formalism as a rigorous formulation of the earlier “empirical potential” approach. They showed that ECP that has the plane-wave pseudowavefunctions as its eigenstates could be derived from the all-electron potential and the core-state wavefunctions and energies. Thus, a nonempirical approach to finding ECP was introduced.

The PK pseudopotential shortcomings are well known [458]: it depends explicitly on the one-electron eigenvalue and outside the core region; the normalized pseudo-orbital (PO) is proportional but not equal to the true orbital. Typically, generation of a pseudopotential proceeds as follows. First, a cutoff distance r_c for the core is chosen (in the case of our example, the oxygen atom, r_c can be taken as 0.5 a.u.; see Fig. 8.2). In a PP approach, all radial $R_{nl}(r)$ orbitals of the valence shell must be nodeless, as for each l , all lower-lying states have to be projected out by the PP. In the case of oxygen, for instance, the $2s$ -PO must be nodeless. An example of such a nodeless $R_{nl}(r)$ that, nevertheless, agrees with the corresponding true AO in the relevant part of space is shown in Fig. 8.3a.

It is, however, impossible to produce two (or more) nodeless orbitals in the same energy range with only a single spherical PP, as for fixed PP, only the angular-momentum term can generate differences. Since PP replaces the potential of a nucleus and the core electrons, it is spherically symmetric, and each angular

momentum l can be treated separately, which leads to nonlocal l -dependent PP $V_l(r)$. Consequently, the total atomic PP usually consists of several components, one for each angular momentum present in the valence space. The PP dependence upon l means that, in general, PP is a nonlocal operator that can be written in semilocal (SL) form:

$$\hat{V}^{\text{PS}} = \sum_{lm} |Y_{lm}(\theta, \varphi)\rangle V_l(r) \langle Y_{lm}^*(\theta, \varphi)| \quad (8.14)$$

where $Y_{lm}(\theta, \varphi)$ are spherical harmonics and $V_l(r)$ is the pseudopotential for the l th angular-momentum component. This is termed semilocal because it is nonlocal in the angular variables, but local in the radial variable: when operating on a function $f(r, \theta', \varphi')$, $\hat{V}^{\text{PS}}$ has the effect [10]

$$[\hat{V}^{\text{PS}} f]_{r, \theta, \varphi} = \sum_{lm} Y_{lm}(\theta, \varphi) V_l(r) \int d(\cos \theta') d\varphi' Y_{lm}(\theta', \varphi') f(r, \theta', \varphi') \quad (8.15)$$

All the PP information is in the radial functions $V_l(r)$. (We note that the HF exchange operator is fully nonlocal both in the angular and in the radial variables.) To generate PP, an all-electron calculation (HF or DFT) of a free atom is performed. The DFT-PP Hamiltonian includes the local (Hartree and exchange-correlation) and semilocal (PP) parts; the HF-PP Hamiltonian includes local (Hartree), nonlocal (exchange), and semilocal (PP) parts. The set of PP parameters is chosen to accurately reproduce the eigenvalues and eigenfunctions of valence states. Clearly, in the region of space in which most of the electronic norm is concentrated, both orbitals must be very close, if not identical. On the other hand, the form of the valence orbitals in the core region, where the core electrons are moving, is less relevant. Otherwise, the core states themselves would play a more important role. In the core region, one can thus allow the pseudo-orbital (PO) to differ from the all-electron orbital (AO) without losing too much accuracy (<http://www.physik.uni-frankfurt.de/~engel/ncpp.html>).

The calculations of real systems (e.g., color centers in ionic crystals, [459]) were made based on the model potential of Abarenkov and Heine [460]:

$$V_M = \begin{cases} V_{\text{val}}(r) - \sum_{lm} |Y_{lm}\rangle A_l(E) \langle Y_{lm}|, & r < r_c \\ -\frac{Z}{r} + V_{\text{val}}(r), & r > r_c \end{cases} \quad (8.16)$$

where V_{val} is the Coulomb and exchange potential due to the valence electrons, Z is the valence charge, and $A_l(E)$ is a constant (in space) function of energy E chosen to make the PO logarithmic derivative equal to that of the true eigenfunction at several atomic eigenvalues. To a high degree of accuracy, $A_l(E)$ may be linearized: $A_l(E) = A_l + B_l E$.

A giant step forward in pseudopotentials was taken by Hamann et al. [456], who introduced norm-conserving pseudopotentials (NCCP). NCCP for angular momentum l is chosen so that:

- (1) The resulting atomic valence PO agrees with the corresponding all-electron (AE) AO for all r larger than some l -dependent cutoff (core) radius

$$R_{nl}^{\text{PS}}(r) = R_{nl}^{\text{AE}}(r) \quad (8.17)$$

- (2) The norm of the orbital is conserved

$$\int_0^{r_{c,l}} |R_{nl}^{\text{PS}}(r)|^2 dr = \int_0^{r_{c,l}} |R_{nl}^{\text{ae}}(r)|^2 dr \quad (8.18)$$

- (3) The logarithmic derivatives of the true and pseudowavefunctions and their first energy derivatives agree for $r > r_c$

Condition 1 automatically implies that the real and pseudovalence eigenvalues agree for a chosen “prototype” configuration, as the eigenvalue determines the asymptotic decay of the orbitals.

Properties (2) and (3) are crucial for the pseudopotential to have optimum transferability among a variety of chemical environments (<http://www.physik.uni-frankfurt.de/~engel/ncpp.html>).

The PP concept has been motivated by the inertness of the atomic core states in binding so that the ionic core of the atom provides a fixed potential in which the valence electrons are moving, independently of the system (atom, molecule, or solid) that is considered. However, in polyatomic systems, the valence states undergo obvious modifications compared to the atomic valence orbitals, even if the polyatomic core potential is given by a simple linear superposition of atomic core potentials. Most notably, the eigenenergies change when packing atoms together, which leads to bonding and antibonding states in molecules and to energy bands in solids. Thus, while PPs are designed to reproduce the valence AOs of some chosen atomic reference configuration (usually the ground state), it is not clear a priori that they will have the same property for all kinds of polyatomic systems and for other atomic configurations. Consequently, one has to make sure that the PP is *transferable* from its atomic reference state to the actually interesting environment. To check the transferability of PP, one has to analyze the sensitivity of the agreement between atomic POs and AOs to the specific eigenenergy in the single-particle equation. One finds that the variation of the logarithmic derivative $R_{nl}^{\text{PS}}(r)/R_{nl}^{\text{ae}}(r)$ with the single-particle energy is determined by the norm contained in the sphere between the origin and r . This is true in particular in the neighborhood of one of the actual atomic eigenvalues ε_{nl} , *that is*, for a bound atomic eigenstate. Thus, as soon as norm conservation is ensured, the POs exactly reproduce the energy dependence of the logarithmic derivative of the AOs for $r > r_{c,l}$. Consequently, one expects the POs to react as the AOs when the valence states experience some energy shift in a polyatomic environment—provided the underlying PPs are norm conserving. This argument supporting the transferability of PPs emphasizes the importance of norm conservation in a very explicit way. In practice, it is, nevertheless, always

recommended to check the transferability explicitly by examination of some suitable atomic excitation process and of the binding properties of simple molecular or crystalline systems (<http://www.physik.uni-frankfurt.de/~engel/ncpp.html>). In the next section, we consider pseudopotentials used in modern periodic calculations.

8.2.2 *Gaussian Form of Effective Core Potentials and Valence Basis Sets in Periodic LCAO Calculations*

The form of ECP used in the condensed-matter applications depends on the basis chosen—PW or LCAO. The numeric pseudopotentials in plane-wave calculations must be used with the density functional that was employed to generate them from a reference atomic state. This is a natural and logical choice whenever one of the plane-wave DFT codes is used. In PW calculations, the valence functions are expanded in Fourier components, and the cost of the calculation scales as a power of the number of Fourier components needed in the calculation. One goal of PP is to create POs that are as smooth as possible and yet are accurate. In PW calculations, maximizing smoothness is to minimize the range of Fourier space needed to describe the valence properties to a given accuracy [10]. Norm-conserving PPs achieve the goal of accuracy, usually at some sacrifice of smoothness. A different approach by Vanderbilt, known as “ultrasoft pseudopotentials”(US) [461], reaches the goal of accurate PW calculations by a transformation that reexpresses the problem in terms of a smooth function and an auxiliary function around each core that represents the rapidly varying part of the density. The generation code for Vanderbilt US pseudopotentials and their library can be found on site <http://www.physics.rutgers.edu/~dhv/uspp>.

Ab initio pseudopotentials for PW calculations of solids can be generated also by the fhiPP package [462]; see also site <http://www.fhi-berlin.mpg.de/th/fhimd/>.

The numerical AO-based DFT code SIESTA (<http://www.uam.es/departamentos/ciencias/fismateriac/siesta/>) employs the same numeric pseudopotentials as plane-wave-based codes. An alternative approach is used in the Slater-orbital-based DFT code ADF (<http://www.scm.com/Doc/Doc2006.01>), where so-called core functions are introduced. They represent the core-electron charge distribution, but are not variational degrees of freedom and serve as fixed core charges that generate the potential experienced by valence electrons [463].

In molecular quantum chemistry Gaussian-function-based computations, effective core potentials were originally derived from a reference calculation of a single atom within the nonrelativistic Hartree–Fock or relativistic Dirac–Fock (see Sect. 8.3) approximations or from some method including electron correlations (CI, for instance). A review of these methods, as well as a general theory of ECPs, is provided in [464, 465].

In this section we discuss those effective core potentials and the corresponding valence basis sets that are used for Gaussian-function-based LCAO periodic computations implemented in the computer codes CRYSTAL [21] and GAUSSIAN [102].

The ECP general form is a sum of a Coulomb term, a local term, and a semilocal term:

$$V_{\text{PS}}(r) = C + V_{\text{loc}} + V_{\text{sl}} = -\frac{Z_N}{r} + \sum_{k=1}^M r^{n_k} C_k \exp(-\alpha_k r^2) + \sum_{l=0}^3 \left[\sum_{k=1}^{M_l} r^{n_{kl}-2} C_{kl} \exp(-\alpha_{kl} r^2) \right] \hat{P}_l \quad (8.19)$$

where Z_N in a Coulomb term is the effective nuclear charge (total nuclear charge minus the number of electrons represented by ECP). The local term is a sum of products of polynomial and Gaussian radial functions. A semilocal term is a sum of products of polynomial radial functions, Gaussian radial functions, and angular-momentum projection operators $\hat{P}_l$. Therefore, to specify semilocal ECP, one needs to include a collection of triplets (coefficient, power of r , and exponent) for each term in each angular momentum of ECP.

Hay and Wadt (HW) ECP [467] are of the general form (8.19). The procedure employed for generation of ECPs includes the following sequence of steps: (1) the “core” orbitals to be replaced and the remaining “valence” orbitals are defined. This step defines whether the small-core (the outermost core electrons are explicitly treated along with the valence electrons) or a large-core HW pseudopotential is generated; (2) the true numerical valence orbitals are obtained from self-consistent nonrelativistic Hartree–Fock (or relativistic Dirac–Fock) calculations for $l = 0, 1, \dots, L$, where L , in general, is one greater than the highest angular-momentum quantum number of any core orbital; (3) smooth, nodeless pseudo-orbitals (PO) are derived from the true Hartree–Fock (Dirac–Fock) orbitals in a manner so that PO behave as closely as possible to HF orbitals in the outer, valence region of the atom; (4) numerical effective core potentials V_l^{PS} are derived for each l by demanding that PO is a solution in the field of V_l with the same orbital energy ε as the Hartree–Fock (Dirac–Fock) orbital; (5) the numerical potentials are fit in analytic form with Gaussian functions, and the total potential is represented as (8.19); and (6) the numerical POs are also fit with Gaussian functions to obtain basis sets for molecular or periodic calculations. In the case of large-core ECP, the primitive Gaussian bases ($3s2p5d$), ($3s3p4d$), and ($3s3p3d$) are tabulated for the first, second, and third transition series atoms, respectively. The figures in brackets mean the number of primitive of Gaussians in ns , np , and $(n-1)d$ contracted AOs for $n = 4, 5, 6$. In the case of small-core ECP, $(n-1)s$, $(n-1)p$ contracted AOs are added and given as the linear combinations of primitive Gaussians. Hay–Wadt ECPs and valence-electron basis sets are also generated for main-group elements: large core—for Na to Xe and Cs to Bi and small core—for K, Ca, Rb, Sr, Cs, and Ba.

The other known ECP and valence-electron basis sets were generated using the procedure, described for Hay–Wadt ECP generation. Durand–Barthelat large-core semilocal ECP [468] and corresponding valence-electron basis sets are generated for $3d$ -transition elements and the main-group elements Li to Kr.

Compact one- and two-Gaussian expansions for the components of the effective potentials of atoms in the first two rows are presented by Stevens–Basch–Krauss [469]. Later, the list of ECP was extended to the third-, fourth-, and fifth-row atoms [470] and includes relativistic ECP (RECP). The pseudo-orbital basis-set expansions for the first two rows of atoms consist of four Gaussian primitives using a common set of exponents for the s and p functions. Analytic SBK RECP are generated in order to reproduce POs and eigenvalues as closely as possible. The semilocal SBK ECP are given by

$$r^2 V_l(r) = \sum_k A_{lk} r^{n_{l,k}} \exp(-B_{l,k} r^2) \quad (8.20)$$

The potentials and basis sets have been used to calculate the equilibrium structures and spectroscopic properties of several molecules. The results compare extremely favorably with the corresponding all-electron calculations.

Stuttgart–Dresden (SD)ECP (formerly Stoll and Preuss ECP) are under constant development [471]. SD semilocal ECPs are written in the form

$$V_{sl} = \sum_{l=0}^3 \left[\sum_{k=1}^{\mu_k} r^{n_{kl}-2} C_{kl} \exp(-\alpha_k r^2) \right] \hat{P}_l \quad (8.21)$$

Note the different convention for the factor $r^{n_{kl}-2}$ compared to (8.19). The database of SD ECP include relativistic ECP (RECP) generated by solving the relativistic Dirac–Fock equation for atoms. Improved SD pseudopotentials exist for many of the main-group elements, and the pseudopotentials are also available for $5d$ and other heavier elements. The most recent ECP parameters, optimized valence-electron basis sets, and a list of references and guidelines for the choice of the pseudopotentials can be found at site <http://www.theochem.uni-stuttgart.de>. SD ECP can be used in periodic LCAO CRYSTAL and GAUSSIAN codes [21, 102].

Pseudopotentials are also used as embedding potentials when some special region of a covalently bonded solid or very large molecule is modeled by a modest-size cluster. The embedding pseudopotentials are considered in the next section.

8.2.3 Separable Embedding Potential

As was noted in the preceding section, the use of atomic pseudopotentials (or effective core potentials–ECPs) considerably simplifies the quantum-mechanical description of polyatomic systems (molecules and crystals) as the much more localized and chemically inert core electrons are simulated by ECP introduction. The choice of the norm-conserving and transferable ECPs ensures that the valence

states are reproduced in the majority of cases as accurately as would be done in all-electron calculations.

The second important application of pseudopotentials is connected with the so-called embedded-cluster model. This model is applied when one is interested in the electronic structure and properties of some small region of a large system such as a localized point defect in a solid, an adsorbed molecule on a solid surface, or an active site in a very large biological molecule. In such a case, one may model the region of interest by cutting a modest-sized but finite cluster out of the larger system and performing the calculation on it. For ionic solids, the surrounding crystal can be modeled by the system of point charges. More difficult is the case when the environment is a covalently bonded system and the boundary between the cluster and environment passes through chemical bonds (covalent or partly covalent). In this case, the distant and nearest parts of an environment should be treated separately [472]. In the distant part, only the electrostatic potential representing the ionic component of an environment should be retained. The nearest part, corresponding to the “broken or dangling bonds,” needs special consideration. Each atom of the cluster boundary surface has unsaturated “dangling bonds” that cause spurious effects unless saturated in some way, usually by adding a hydrogen or pseudoatoms there [473]. This is better than leaving the dangling bond, but clearly, the termination is still imperfect in the sense that the bond to the attached atom is different from the bond to whatever atom is situated there in the real system [472]. Use of the embedding potentials (EPs) to saturate dangling bonds of the cluster gives a cluster surface bond identical to that in the real large system.

Recently introduced new separable potentials [472, 474] have several kinds of applications: (1) when some special region of a covalently bonded solid or very large molecule is modeled by a modest-sized cluster, each dangling bond at the cluster surface can be saturated in a way that exactly reproduces the bond in the complete system; (2) a similar approach can be used at the matching surface in an embedding scheme for calculations on the same type of systems; and (3) application to atomic effective core potentials where the new potential operator avoids the possibility of “ghost” states that sometimes plague the widely used pseudopotentials.

The important property of the introduced embedding potential is its separability. Let the nonlocal operator $\hat{V}(\mathbf{r})$ depend on the space variable $\mathbf{r}$ only and be represented by the integral operator $\hat{V}$:

$$\hat{V}\psi(\mathbf{r}) = \int v(\mathbf{r}, \mathbf{r}')\psi(\mathbf{r}')d\mathbf{r}' \quad (8.22)$$

with the kernel $v(\mathbf{r}, \mathbf{r}')$. Expanding the kernel in both arguments with the complete orthonormal set of functions $\varphi_i(\mathbf{r})$ ($i = 1, 2, 3, \dots$), the following representation of the potential can be obtained:

$$\hat{V} = \sum_{i,j=1}^{\infty} |\varphi_i\rangle V_{ij} \langle \varphi_j| \quad (8.23)$$

where V_{ij} is the infinite Hermitian matrix. If this matrix has a finite rank k , then only k of its eigenvalues are not equal to zero, and the corresponding potential has the form

$$\hat{V}_{\text{sep}} = \sum_{i=1}^k |\chi_i\rangle \mu_i \langle \chi_i| \quad (8.24)$$

where $\chi_i(\mathbf{r})$ and μ_i are eigenfunctions and eigenvalues of the potential. Equation (8.24) defines the separable potential as a finite sum of single-state projectors ($|\chi_i\rangle\langle\chi_i|$) with constant weights μ_i . A separable operator is an operator with a finite-dimensional functional space for its range. If one employs another orthonormal basis set $\varphi_i (i = 1, 2, \dots, k)$ that spans the same functional space as the set $\chi_i(\mathbf{r}) (i = 1, 2, \dots, k)$, the separable potential will have the nondiagonal form

$$\hat{V}_{\text{sep}} = \sum_{i,j=1}^k |\varphi_i\rangle V_{ij} \langle \varphi_j| \quad (8.25)$$

but with finite sum over i, j . The difference between the separable potential and the potential of the general form is that the separable potential with a suitable choice of the basis could be transformed to the form (8.24) or (8.25) and the potential of the general form could not.

As an example of separable potentials, we mention the semilocal ECP (see (8.14)) which have a form similar to (8.24), but where $\mu_i = V_i(r)$ are functions of the radial variable. These semilocal potentials are separable only in the angular variables (in which these potentials are nonlocal) as the separability is the property of nonlocal potentials.

Separable nonlocal ECPs were extensively studied [458, 475–478]. The nonlocal separable potential application is complicated by the problem of “ghost states” [479], *that is*, extra bound states with levels, under the reference atomic eigenenergy. For semilocal ECPs, used in modern computer LCAO codes, this problem does not occur [477]; for the embedding potential, this problem has to be taken into account.

Let us consider a Hamiltonian $\hat{H}_0$ with eigenfunctions Ψ_i^0 and eigenvalues E_i^0 . Suppose we have an arbitrary set of orthonormal functions Ψ_p and an arbitrary set of real numbers $E_p (p = 1, \dots, n)$. The aim is to develop another Hamiltonian

$$\hat{H}_{\text{sep}} = \hat{H}_0 + \hat{V}_{\text{sep}} \quad (8.26)$$

with separable potential $\hat{V}_{\text{sep}}$ so that n eigenfunctions and eigenvalues of $\hat{H}_{\text{sep}}$ are exactly Ψ_p and E_p , whereas all other eigenvalues $E_i, i > n$ of $\hat{H}_{\text{sep}}$ are equal to eigenvalues of $\hat{H}_0$.

Of course, eigenfunctions $\Psi_i, (i > n)$ of $\hat{H}_{\text{sep}}$ will differ from eigenfunctions Ψ_i^0 of $\hat{H}_0$ because the former are orthogonal to $\Psi_p, (p \leq n)$ and the latter to Ψ_p^0 .

The transformation $\hat{H}_0$ into $\hat{H}_{\text{sep}}$ could be done in two steps.

In the first step the similarity transformation $\hat{H}' = \hat{U} \hat{H}_0 \hat{U}^\dagger$ with a unitary operator $\hat{U}$ is made, which changes the eigenfunctions and leaves eigenvalues unchanged. To find the desired similarity transformation, the following auxiliary problem is considered: a unitary operator $\hat{U}$ is found that transforms one set of orthonormal functions Ψ_p^0 into another set of orthonormal functions Ψ_p :

$$\hat{U} \Psi_p^0 = \alpha_p \Psi_p, \quad |\alpha_p| = 1, \quad p = 1, 2, \dots, n \quad (8.27)$$

and there is no linear dependence among functions Ψ_p^0 and Ψ_p , *that is*, the dimension of functional space spanned by both sets of functions together is equal to $2n$. The operator $\hat{U}$ is taken in the form $\hat{U} = \hat{I} - \hat{R}$, and $\hat{R} = \sum_{p,q=1}^n |\chi_p\rangle T_{pq} \langle \chi_q|$ is a separable operator with the smallest possible dimension. Dropping the mathematical details given in [472], we write the explicit form of the operator $\hat{R}$:

$$\hat{R} = \sum_{p,q=1}^n |\Psi_p^0 - \alpha_p \Psi_p\rangle \{Q^{-1}\}_{pq} \langle \Psi_q^0 - \alpha_q \Psi_q| \quad (8.28)$$

where $\chi_p = \Psi_p^0 - \alpha_p \Psi_p$ and $Q_{pq} = \langle \chi_p | \Psi_q^0 \rangle = \delta_{pq} - \alpha_p^* \langle \Psi_p | \Psi_q^0 \rangle$. The second step is the energy-shift transformation that changes specified eigenvalues only:

$$\begin{aligned} \hat{H}_{\text{sep}} &= \hat{H}' + \sum_{p=1}^n |\Psi_p\rangle (E_p - E_p^0) \langle \Psi_p| \\ &= \hat{U} \hat{H}_0 \hat{U}^\dagger + \sum_{p=1}^n |\Psi_p\rangle (E_p - E_p^0) \langle \Psi_p| \end{aligned} \quad (8.29)$$

Hence, the potential $\hat{V}_{\text{sep}}$ can be written as

$$\hat{V}_{\text{sep}} = \hat{H}_{\text{sep}} - \hat{H}_0 = \hat{R} \hat{H}_0 \hat{R}^\dagger - \hat{R} \hat{H}_0 - \hat{H}_0 \hat{R}^\dagger + \sum_{p=1}^n |\Psi_p\rangle (E_p - E_p^0) \langle \Psi_p| \quad (8.30)$$

This potential is separable with dimension n , *that is*, can be represented in the form

$$\hat{V}_{\text{sep}} = \sum_{i,j}^{3n} |f_i\rangle V_{ij} \langle f_j| \quad (8.31)$$

where the expression for V_{ij} can be found from expressions of $\hat{R} \hat{H}_0$, $\hat{H}_0 \hat{R}^\dagger$, and $\hat{R} \hat{H}_0 \hat{R}^\dagger$. Although all equations were developed for arbitrary phase factors α_p , in applications, the real orbitals are used. For the sake of simplicity, all the phase factors α_p can be selected to be real, which makes the separable potential real

as well. The signs of Ψ_p and Ψ_p^0 are selected so that $\langle \Psi_p | \Psi_p^0 \rangle \geq 0$ and all $\alpha_p = -1$ to make $\hat{V}_{\text{sep}} \rightarrow 0$ when $G \rightarrow G^0$ (G is a collection of $\Psi_p, E_p, p = 1, 2, \dots$, and G^0 is a similar collection of Ψ_p^0, E_p^0).

The separable embedding potential (8.31) was applied to model the single chemical bond between the atom A of the cluster and the atom B of the cluster environment [472]. To simulate the effect of the cluster environment, the atom B is replaced by a pseudoatom B_{PS} at the same position as the actual atom B . The influence of the pseudoatom on the cluster is described by the potential that was assumed to have the following form:

$$\hat{V}_{\text{psat}} = \hat{V}_H + \hat{V}_{\text{sl}} + \hat{V}_{\text{sep}} \quad (8.32)$$

Here, $\hat{V}_H = -1/r$ is the hydrogen potential (in a.u.), responsible for the asymptotic behavior of the potential; $\hat{V}_{\text{sl}}$ is a semilocal potential

$$\hat{V}_{\text{sl}} = \sum_{lm} V_l(r) |Y_{lm}\rangle \langle Y_{lm}| \quad (8.33)$$

and $\hat{V}_{\text{sep}}$ is a case $n = 1$ separable potential (8.31) defined by the Hamiltonian $\hat{H}_0$, the energy E_1^0 , and the wavefunction Ψ_1^0 of this Hamiltonian ground state and by the energy E_1 and the wavefunction Ψ_1 of the operator $\hat{H}_0 + \hat{V}_{\text{sl}}$, as $\hat{H}_0$ was taken the following:

$$\hat{H}_0 = -\frac{1}{2}\Delta + \hat{V}_H + \hat{V}_{\text{sl}} \quad (8.34)$$

where $\hat{V}_{\text{sl}}$ is selected so as to reproduce the spectrum of the excited states of the atom B similarly to what is usually done in the calculation of the effective atomic core potentials. The wavefunction Ψ_1^0 of the ground state of this Hamiltonian is a spherically symmetrical $1s$ function, and it is not at all a directed hybrid orbital of the atom B that makes the single bond with the atom A . The separable potential $\hat{V}_{\text{sep}}$ being added to $\hat{H}_0$ will change the ground-state wavefunction Ψ_1^0 for function Ψ_1 without changing the excited-state spectrum. Therefore, Ψ_1 should be considered as a hybrid orbital of the atom B that is not known. However, the bond orbital φ_{bond} can be found. The new localization criterion was proposed to calculate the localized on bond $A-B$ orbital φ_{bond} . This criterion is based on the maximization of the single-orbital contribution to the Wiberg index W_{AB} defined by (4.137). The one-electron density matrix is calculated in the bases of AOs orthogonalized according to Löwdin procedure [215]. This bond orbital depends on Ψ_1 implicitly, and in [472], a method to calculate φ_{bond} and its effective energy E_{bond} was developed. The transferability of the separable embedding potential used seems very likely as the developed method of pseudopotential calculation results in the one-center potential (all the components of this potential, including $\hat{V}_{\text{sep}}$, are centered on the atom B). This is demonstrated by use of the proposed separable potential (8.32) for the pseudosilicon atom that is to substitute the $-\text{SiH}_3$ radical in X-SiH_3 molecules (X was taken to be H, F, Cl,

Br, and I). In all these molecules, the hydrogen or halogen constitutes the single chemical bond with Si. This bond is broken when the radical —SiH_3 is removed, and it could be saturated with the pseudosilicon atom so that the original five-atom molecule would be replaced by the diatomic molecule X—Si_{ps} . The angles between bonds in SiH_3X molecules vary only a little, and the perfect tetrahedron angle was used for all molecules. The Si–H bond length in these molecules is also approximately equal to that in the SiH_4 molecule, and silicon–halogen bond length varies considerably (the experimental values for silicon–halogen bond lengths were taken from diatomic Si–Hal molecules). The potential (8.32) was generated for the pseudosilicon atom to make the bond in the two-electron diatomic molecule H—Si_{ps} the same as the single chemical bond H—Si in the SiH_4 molecule; this potential is centered at the Si atom.

The potential-generation procedure consists of several stages. In the first stage, the all-electron HF calculations on the SiH_4 molecule were performed. The canonical HF orbitals, orbital energies, and the total density matrix were obtained in the GTO basis. In the second stage, the noncanonical HF orbital φ_{bond} localized on the selected Si–H bond was calculated using the Wiberg index for the localization criteria. The maximum localizing functional value obtained was 0.965, which is close enough to the maximum possible value 1 for the single covalent bond. In the third stage, the semilocal potential $\hat{V}_{\text{sl}}$ was generated so that the excited energy levels of the equation

$$\left(-\frac{1}{2}\Delta - \frac{1}{r} + \hat{V}_{\text{sl}}\right)\psi_{nlm}^0(\mathbf{r}) = E_{nl}^0\psi_{nlm}^0 \quad (8.35)$$

coincide with unoccupied energy levels of the neutral silicon atom ($E_{2s}^0 = E(\text{Si})_{4s}$, $E_{2p}^0 = E(\text{Si})_{4p}$, $E_{3d}^0 = E(\text{Si})_{3d}$, and so on). No adjustment was done for the E_{1s}^0 energy level, and it could be quite different from $E(\text{Si})_{3s}$. In the fourth and final stage, the function ψ_1 and the energy E_1 were determined, and the pseudosilicon potential was obtained. The obtained potential of the pseudosilicon atom was used to calculate the diatomic molecules X—Si_{ps} ($\text{X} = \text{F}, \text{Cl}, \text{Br}, \text{I}$). The properties of the bond and the state of the halogen atom in the diatomic molecule could be compared with those in the real five-atom molecule. This comparison will show whether the same pseudosilicon potential could be used in all considered molecules, *that is*, whether the generated pseudosilicon potential is transferable. The dipole moment of the bond was chosen for the bond property and the atomic charge for the halogen property. For the diatomic molecule, the dipole moment of the bond is the dipole moment of the molecule itself. However, for the five-atom molecule, the dipole moment of the particular bond is not defined a priori. To make the comparison possible, several assumptions were used that are natural enough. It was assumed that the dipole moment of every five-atom molecule SiH_3X is the sum of the dipole moment of the X—Si bond and the dipole moment of the SiH_3 radical. Next, it was assumed that the dipole moment of the (SiH_3) radical is the same in all five molecules. The latter assumption can be considered as the “frozen bond” approximation, *that is*, the neglect of the radical polarization when the X—Si bond

Table 8.4 The dipole moments (a.u) [472]

	Theor.1 ^a	Theor.2 ^b	Theor.3 ^c	Expt.
SiH ₃ F	1.226	0.555	0.527	0.511
SiH ₃ Cl	0.899	0.644	0.631	0.515
SiH ₃ Br	0.267	0.502	0.533	0.519
SiH ₃ I	0.257	0.536	0.560	

^aThe bond is saturated with the hydrogen^bThe bond is saturated with the pseudosilicon^cAll-electron Hartree–Fock calculations**Table 8.5** The charge on atom A, A = H, F, Cl, Br, I [472]

	Theor.1 ^a	Theor.2 ^b	Theor.3 ^c
SiH ₄	0.000	−0.157	−0.149
SiH ₃ F	−0.380	−0.523	−0.687
SiH ₃ Cl	−0.278	−0.398	−0.416
SiH ₃ Br	−0.032	−0.035	−0.040
SiH ₃ I	−0.097	−0.263	−0.352

^aThe bond is saturated with the hydrogen^bThe bond is saturated with the pseudosilicon^cAll-electron Hartree–Fock calculations

is changing. Other details of the dipole-moment calculations can be found in [472]. To improve the agreement of the calculated dipole moments with the experimental data, one *d*-orbital was added to the GTO 6-311G basis of silicon and halogen atoms.

In Tables 8.4 and 8.5, the dipole moments and Mulliken atomic charges found in the all-electron HF calculations are compared with those obtained with the use of a pseudosilicon atom and a hydrogen atom to saturate the bond. The disagreement between experimental and HF data is explained by the neglect of the correlation effects and in the case of a SiH₃I molecule the neglect of relativistic effects. The analysis of Table 8.4 allows us to conclude that the pseudosilicon potential generated for one molecule (SiH₄) to represent the SiH₃ radical could be employed in calculations of other molecules (SiH₃X, X = F, Cl, Br, I) with the same radical.

From Table 8.5, it follows that the correlation between charges calculated with different methods is similar to that for the dipole moments. However, it should be remembered that atomic charges are not physically observable quantities, and they strongly depend on their definition and on the basis employed in calculations.

Approximations to the exact (in the Hartree–Fock approximation) separable embedding potential were introduced in [474] that enable one to incorporate this potential into existing molecular calculation packages. The test calculations on the (CH₃)₂O molecule were performed that showed good accuracy of the potential.

So far, the formulation of pseudopotentials has been strictly nonrelativistic, so that the issue of heavy elements still remains to be addressed. In the next section we consider relativistic pseudopotentials.

8.3 Relativistic Effective Core Potentials and Valence Basis Sets

8.3.1 *Relativistic Electronic-Structure Theory: Dirac–Hartree–Fock and Dirac–Kohn–Sham Methods for Molecules*

Heavy-element systems are involved in many important chemical and physical phenomena. However, they still present difficulties to theoretical study, especially in the case of solids containing atoms of heavy elements (with the nuclear charge $Z \geq 50$). In this short description of relativistic electronic-structure theory for molecular systems, we follow [480] and add a more detailed explanation of the Dirac–Kohn–Sham (DKS) method. For a long time, the relativistic effects underlying in heavy atoms had not been regarded as such an important effect for chemical properties because the relativistic effects appear primarily in the core atomic region. However, now the importance of the relativistic effects, which play essential and vital roles in the total natures of electronic structures for heavy-element molecular and periodic systems, is recognized [480].

To treat the relativistic effect theoretically, the Dirac Hamiltonian should be applied instead of the nonrelativistic Schrödinger Hamiltonian. The Dirac one-particle Hamiltonian has the form

$$\hat{h}_D = c\boldsymbol{\alpha} \cdot \hat{\mathbf{p}} + (\beta - 1)c^2 + V(\mathbf{r}) \quad (8.36)$$

where c is the speed of light, $V(\mathbf{r})$ is the external potential, and $\hat{\mathbf{p}} = -i\nabla$ is the momentum operator. The 4×4 Dirac matrices $\boldsymbol{\alpha}$ and β in (8.36) are given by

$$\alpha^t = \begin{pmatrix} 0_2 & \sigma_t \\ \sigma_t & 0_2 \end{pmatrix}, \quad t = (x, y, z), \quad \beta = \begin{pmatrix} I_2 & 0_2 \\ 0_2 & -I_2 \end{pmatrix} \quad (8.37)$$

with a 2×2 Pauli spin matrix, σ_t

$$\sigma_x = \begin{pmatrix} 0 & 1 \\ 1 & 0 \end{pmatrix}, \quad \sigma_y = \begin{pmatrix} 0 & -i \\ i & 0 \end{pmatrix}, \quad \sigma_z = \begin{pmatrix} 1 & 0 \\ 0 & -1 \end{pmatrix} \quad (8.38)$$

Here, 0_2 and I_2 are zero and identity 2×2 matrices.

The free-particle Dirac Hamiltonian provides a physical structure that the eigenvalue spectrum $\{E_k\}$ consists of two parts. The states of the higher-energy spectrum, where $E_k \geq +mc^2$, are called the positive-energy states and comprise states corresponding to those found in the nonrelativistic theory. The second branch of the eigenvalue spectrum consists of states with energy less than $-mc^2$, and in a second-quantized theory, they can be interpreted as states of positrons and are called the negative-energy states.

To apply the Dirac theory to the many-particle system, the one-particle Dirac operator (8.36) is augmented by the Coulomb or Coulomb–Breit operator as the two-particle term, g_{ij} , to produce the Dirac–Coulomb (DC) or Dirac–Coulomb–Breit (DCB) Hamiltonian derived from the quantum electrodynamics [480–482]:

$$g_{ij} = \begin{cases} g_{ij}^c = \frac{1}{r_{ij}}, & \mathbf{r}_{ij} = \mathbf{r}_i - \mathbf{r}_j, \quad r_{ij} = |\mathbf{r}_{ij}| \\ g_{ij}^{CB} \end{cases} \quad (8.39)$$

where

$$g_{ij}^{CB} = \frac{1}{r_{ij}} - \frac{1}{2} \left(\frac{(\boldsymbol{\alpha}_i \boldsymbol{\alpha}_j)}{r_{ij}} + \frac{(\boldsymbol{\alpha}_i \mathbf{r}_{ij})(\boldsymbol{\alpha}_j \mathbf{r}_{ij})}{r_{ij}^3} \right) \quad (8.40)$$

By applying the independent particle approximation to many-particle relativistic DC or DCB Hamiltonians, one obtains the four-component Dirac–Hartree–Fock (DHF) method with large- and small-component spinors treated explicitly.

The DHF wavefunction Ψ is given as the Slater determinant with N_e one-particle spinors ($\psi_i(\mathbf{r})$, $i = 1, \dots, N_e$), where N_e represents the number of electrons. The one-particle spinor $\psi_i(\mathbf{r})$ is the four-component vector whose components are the scalar wavefunctions,

$$\psi_i = \begin{pmatrix} \psi_i^{2L} \\ \psi_i^{2S} \end{pmatrix} = \begin{pmatrix} \psi_{1i}^L \\ \psi_{2i}^L \\ \psi_{3i}^S \\ \psi_{4i}^S \end{pmatrix} \quad (8.41)$$

The two-component electron functions ψ_i^{2L} and ψ_i^{2S} are called the large-component and small-component spinors, respectively, which are expanded in the basis spinors χ^L and χ^S .

The matrix DHF–LCAO equation for closed-shell systems is given as

$$\mathbf{FC} = \mathbf{SCE} \quad (8.42)$$

where $\mathbf{C}$ is a matrix of molecular spinor coefficients, $\mathbf{E}$ is a diagonal spinor(orbital) energy matrix, $\mathbf{S}$ is an overlap matrix,

$$\mathbf{S}_{\mu\nu} = \begin{pmatrix} \langle \chi_\mu^L | \chi_\nu^L \rangle & 0 \\ 0 & \langle \chi_\mu^S | \chi_\nu^S \rangle \end{pmatrix} \quad (8.43)$$

and the Fock matrix $\mathbf{F}$ is given by

$$\mathbf{F}_{\mu\nu} = \begin{pmatrix} \mathbf{V}_{\mu\nu}^{LL} + \mathbf{J}_{\mu\nu}^{LL} - \mathbf{K}_{\mu\nu}^{LL} & c\mathbf{\Pi}_{\mu\nu}^{LS} - \mathbf{K}_{\mu\nu}^{LS} \\ c\mathbf{\Pi}_{\mu\nu}^{SL} - \mathbf{K}_{\mu\nu}^{SL} & \mathbf{V}_{\mu\nu}^{SS} + \mathbf{J}_{\mu\nu}^{SS} - \mathbf{K}_{\mu\nu}^{SS} - 2c^2\mathbf{S}_{\mu\nu}^{SS} \end{pmatrix} \quad (8.44)$$

The matrices $\mathbf{\Pi}_{\mu\nu}^{X\bar{X}}$, $\mathbf{V}_{\mu\nu}^{XX}$, $\mathbf{J}_{\mu\nu}^{XX}$, and $\mathbf{K}_{\mu\nu}^{XX}$ ($X, Y = L$ or S , $\bar{L} = S$, and $\bar{S} = L$) are the kinetic-energy integral, the nuclear-attraction integral, and the Coulomb integral, respectively, defined by

$$\mathbf{\Pi}_{\mu\nu}^{X\bar{X}} = \langle \chi_\mu^X | \sigma \mathbf{p} | \chi_\nu^{\bar{X}} \rangle \quad (8.45)$$

$$\mathbf{V}_{\mu\nu}^{X\bar{X}} = \langle \chi_\mu^X | V^{nuc} | \chi_\nu^{\bar{X}} \rangle \quad (8.46)$$

$$\mathbf{J}_{\mu\nu}^{XX} = \sum_{Y=L,S} \sum_{\lambda\sigma} \mathbf{P}_{\lambda\sigma}^{YY} \left(\chi_\mu^{2X} \chi_\nu^{2X} | \chi_\lambda^{2Y} \chi_\sigma^{2Y} \right) \quad (8.47)$$

and

$$\mathbf{K}_{\mu\nu}^{XY} = \sum_{\lambda\sigma} \mathbf{P}_{\lambda\sigma}^{XY} \left(\chi_\mu^{2X} \chi_\nu^{2X} | \chi_\lambda^{2Y} \chi_\sigma^{2Y} \right) \quad (8.48)$$

The density matrix $\mathbf{P}_{\lambda\sigma}^{XY}$ is calculated as

$$\mathbf{P}_{\lambda\sigma}^{XY} = \sum_i^{\text{occ}} C_{i\lambda}^X C_{i\sigma}^{Y*} \quad (8.49)$$

where the negative-energy states are ignored. Even applying the four-component single-configuration (SCF) approximation, Dirac–Hartree–Fock–Breit (DHFB) or DHF methods, to calculation of heavy-atom molecules (followed by transformation of two-electron integrals to the basis of molecular spinors) is not always an easy task because a very large set of primitive atomic basis functions can be required for such all-electron four-component SCF calculations.

In the high- Z case the effects of relativity can be just as important as those of electron correlation, making it necessary to develop efficient methods for the simultaneous treatment of correlation and relativity [483]. Such a treatment can be made in the framework of post-DHF methods (very complicated in the practical realization) or relativistic DFT theory.

Although the DFT method has been extensively applied to nonrelativistic calculations, the four-component DFT approaches have only recently appeared (see the book [325] and the review [483] and references therein). Relativistic versions of the Kohn–Sham equations have been developed based on the relativistic extension of the Hohenberg–Kohn theory [484].

The one-electron effective Hamiltonian for the Dirac–Kohn–Sham (DKS) method, as a relativistic extension of the conventional KS approach, takes the form

$$\hat{h}_{\text{DKS}} = \hat{h}_D + \mathbf{V}_H + \mathbf{V}_{\text{XC}} + \beta \sigma \frac{\delta E_{\text{XC}}[\rho, \mathbf{m}]}{\delta \mathbf{m}(\mathbf{r})} \quad (8.50)$$

where $\hat{h}_D$ is the one-electron Dirac operator (8.36) and $\mathbf{V}_H = \int \frac{\rho(\mathbf{r}')}{|\mathbf{r}-\mathbf{r}'|} d\mathbf{r}'$ is the Hartree potential, defined by the electron charge spin density $\rho(\mathbf{r})$. In contrast to the nonrelativistic theory, the relativistic exchange–correlation potential consists of the spin-independent part (the functional derivative of the exchange–correlation

energy functional with respect to total density $\frac{\delta E_{XC}}{\delta \rho}$ and the spin-dependent part $\beta \sigma \frac{\delta E_{XC}}{\delta \mathbf{m}(\mathbf{r})}$, where $\mathbf{m}(\mathbf{r})$ is the spin magnetization vector [485]. The latter is defined as $\mathbf{m}(\mathbf{r}) = \sum_i^{\text{occ}} \psi_i^* \boldsymbol{\sigma} \psi_i$, where ψ_i are two-component spinors $\psi_i = \begin{pmatrix} \psi_{i\alpha} \\ \psi_{i\beta} \end{pmatrix}$ and $\boldsymbol{\sigma} = (\sigma_x, \sigma_y, \sigma_z)$ is the vector of the Pauli spin matrices. In the so-called collinear approach, the vector $\mathbf{m}(\mathbf{r})$ is projected on the z-axis to define the spin density $s(\mathbf{r}) = m_S(\mathbf{r}) = \sum_i^{\text{occ}} \psi_i^* \sigma \psi_i = \sum_i^{\text{occ}} (\psi_{i\alpha}^* \psi_{i\alpha} - \psi_{i\beta}^* \psi_{i\beta})$. The total density is given by

$$\rho(\mathbf{r}) = \sum_i^{\text{occ}} \psi_i^* \psi_i = \sum_i^{\text{occ}} (\psi_{i\alpha}^* \psi_{i\alpha} + \psi_{i\beta}^* \psi_{i\beta}) \quad (8.51)$$

where positron states are excluded by employing the so-called no-sea approximation. The DKS equation is then the matrix pseudoeigenvalue equation by introducing basis set expansion as

$$\hat{\mathbf{h}}^{\text{DKS}} \mathbf{C} = \mathbf{S} \mathbf{C} \mathbf{E} \quad (8.52)$$

where $\hat{\mathbf{h}}^{\text{DKS}}$ takes the form of a Fock matrix

$$\mathbf{h}_{\mu\nu}^{\text{DKS}} = \begin{pmatrix} \mathbf{V}_{\mu\nu}^{LL} + \mathbf{J}_{\mu\nu}^{LL} - \mathbf{V}_{(\text{XC})\mu\nu}^{LL} & c \mathbf{\Pi}_{\mu\nu}^{LS} \\ c \mathbf{\Pi}_{\mu\nu}^{SL} & \mathbf{V}_{\mu\nu}^{SS} + \mathbf{J}_{\mu\nu}^{SS} - \mathbf{V}_{(\text{XC})\mu\nu}^{SS} - 2c^2 \mathbf{S}_{\mu\nu}^{SS} \end{pmatrix} \quad (8.53)$$

In (8.53), $\mathbf{V}_{(\text{XC})\mu\nu}^{XX}$ is the exchange–correlation potential defined by

$$\mathbf{V}_{(\text{XC})\mu\nu}^{XX} = \left\langle \chi_\mu^X \left| \frac{\delta E_{XC}}{\delta \rho} + \frac{\delta E_{XC}}{\delta \mathbf{m}(\mathbf{r})} \right| \chi_\nu^X \right\rangle \quad (8.54)$$

During the last decade, good progress was attained in four-component techniques for molecules (see [480, 486, 487] and references therein) that allowed one to reduce efforts in calculation and transformation of two-electron matrix elements with small components of four-component molecular spinors. The straightforward DHF and DKS methods with the four-component spinors were implemented in several *ab initio* MO LCAO programs: MOLFDIR [488], DIRAC [489], and BERTHA [490]. However, fully relativistic DFT calculations on molecules containing more than one or two heavy atoms are not yet routine. The efficient computational scheme for the Gaussian-based fully relativistic DHF and DKS methods is proposed in [480] and applied to hydrides MH and dimers M_2 ($M=\text{Cu, Ag, Au}$).

As the fully relativistic (four-component) calculations demand severe computational efforts, several quasirelativistic (two-component) approximations have been proposed in which only large components are treated explicitly. The approaches with perturbative treatment of relativistic effects [491] have also been developed in which a nonrelativistic wavefunction is used as reference. The Breit–Pauli (BP) approximation uses the perturbation theory up to the $(p/mc)^2$ term and gives

reasonable results in the first-order perturbation calculation. Unfortunately, this method cannot be used in variational treatment. One of the shortcomings of the BP approach is that the expansion in $(p/mc)^2$ diverges in the case where the electronic momentum is too large, for example, for a Coulomb-like potential [480]. The zeroth-order regular approximation (ZORA) [493] can avoid this disadvantage by expanding in $E/(2mc^2 - V)$ up to first order. The ZORA Hamiltonian is variationally stable. However, the Hamiltonian obtained by a higher-order expansion has to be treated perturbatively, similarly to the BP Hamiltonian.

Two recently developed quasirelativistic approaches are considered in [480]. In particular, in the RESC method (the relativistic scheme by eliminating small components), the Hamiltonian is separated into the spin-averaged (scalar-relativistic, which can be called the one-component approximation) and spin-dependent parts. The RESC approach has several advantages. It is variationally stable. This method can easily be implemented in various nonrelativistic *ab initio* programs, and the relativistic effect is considered on the same footing with the electron-correlation effect. RESC has been applied to various systems in ground and excited states. As the energy gradient of the RESC method is also available, it is possible to study the chemical reaction in the heavy-element systems (as an example, the ionization of OsO_4 is considered in [480]).

While accurate relativistic (both four- and two-component) calculations of simple heavy-atom molecules can be performed on modern computers, the relativistic calculations of periodic systems are made mainly using relativistic effective core potential (RECP). We consider these potentials in the next section.

8.3.2 Relativistic Effective Core Potentials

The two-component RECP approximation was suggested originally by Lee et al. [492] and is widely used in molecular calculations (see [471, 494, 495]). There are several reasons for using RECPs in calculations of complicated heavy-atom molecules, molecular clusters, and periodic solids. As the nonrelativistic ECP approaches, the RECP approaches allow one to exclude the large number of chemically inactive electrons from calculations and treat explicitly only valence and outermost core electrons. The oscillations of the valence spinors are usually smoothed in heavy-atom cores simultaneously with exclusion of small components from the explicit treatment (quasirelativistic approximation). As a result, the number of primitive basis functions can be essentially reduced; this is especially important for calculation and transformation of two-electron integrals when studying many atomic systems with very heavy elements including lanthanides and actinides. The RECP method is based on a well-developed earlier nonrelativistic technique of pseudopotential calculations; however, effective scalar-relativistic and spin-orbit interaction effects are taken into account by means of the RECP operator. Post-DHF correlation calculations with RECPs are performed in a natural way in the basis of spin-orbitals (and not of spinors as in all-electron four-component relativistic calculations) even for the cases when the Dirac–Coulomb–Breit (DCB) Hamiltonian

is used [496]. Note, however, that the DCB technique with the separated spin-averaged and spin-dependent terms also has been developed [497], but it can be efficiently applied only in the cases when spin-dependent effects can be neglected both for valence and for core shells. In the RECP method, the interactions with the excluded inner-core shells (spinors!) are described by spin-dependent potentials, whereas the explicitly treated valence and outer-core shells can be described by spin-orbitals. This means that some “soft” way of accounting for the core-valence orthogonality constraints is applied in the latter case [498]. Meanwhile, the strict core-valence orthogonality can be retrieved after the RECP calculation by using the restoration procedures described below. The use of the spin-orbitals allows one to reduce dramatically the expenses at the stage of correlation calculation. Thus, many complications of the DC or DCB calculations are avoided when employing RECPs.

When core electrons of a heavy atom do not play an active role, the effective Hamiltonian with RECP can be presented in the form

$$\mathbf{H}^{\text{Ef}} = \sum_{i_v} [\mathbf{h}^{\text{Schr}}(i_v) + \mathbf{U}^{\text{Ef}}(i_v)] + \sum_{i_v > j_v} \frac{1}{r_{i_v j_v}} \quad (8.55)$$

This Hamiltonian is written only for a valence subspace of electrons that are treated explicitly and denoted by indices i_v and j_v (large-core approximation). As in the case of nonrelativistic pseudopotentials, this subspace is often extended by inclusion of some outermost core shells for better accuracy (small-core approximation), but below, we consider them as the valence shells if these outermost core and valence shells are not treated using different approximations. In (8.55), $\mathbf{h}^{\text{Schr}}$ is the one-electron Schrödinger Hamiltonian:

$$\mathbf{h}^{\text{Schr}} = -\frac{1}{2}\nabla^2 - \frac{Z_{ic}}{r} \quad (8.56)$$

where Z_{ic} is the charge of the nucleus decreased by the number of inner-core electrons. $\mathbf{U}^{\text{Ef}}$ in (8.55) is an RECP (relativistic pseudopotential) operator that is usually written in the radially local (semilocal) [494] or separable [499] approximations when the valence pseudospinors are smoothed in the heavy-atom cores. In LCAO calculations of heavy-atom molecules among the radially local RECPs, the shape-consistent (or norm-conserving) RECP approaches [494] are employed, and “energy-consistent” pseudopotentials by the Stuttgart–Dresden–Cologne group are also actively used [471, 495, 500]. The latter are now applied also in LCAO calculations of periodic systems with modified valence basis sets (see Sect. 8.3.5). To generate “energy-consistent” RECP, the direct adjustment of two-component pseudopotentials is made (scalar-relativistic + spin-orbit potentials) to atomic total energy valence spectra. The latter is derived from the four-component multiconfiguration DHF all-electron atomic calculations based on the DCB Hamiltonian. The “energy-consistent” RECPs are now tabulated for all the elements of periodic table at the site www.theochem.uni-stuttgart.de. The adjustment of the pseudopotential parameters has been done in fully numerical atomic calculations; valence basis

sets have been generated *a posteriori* via energy optimization. The complete set of potentials includes one-component (nonrelativistic and scalar-relativistic) effective core potentials (ECPs) and spin-orbit (SO) and core-polarization potentials (CPPs); only the one-component ECPs are listed in full. The “energy-consistent” pseudopotentials are under continuous development and extension [500, 501], and the corresponding Gaussian basis sets are published [502–504].

In plane-wave calculations of solids and in molecular dynamics, the separable pseudopotentials [88, 476, 499] are more popular now because they provide linear scaling of computational effort with the basis-set size in contrast to the radially local RECPs. Moreover, the nonlocal Huzinaga-type “*ab initio* model potentials” [505–507] conserving the nodal structure for the valence spinors are often applied. Contrary to the four-component wavefunction used in DC(B) calculations, the pseudowavefunction in the RECP case can be both two and one components. The RECP operator simulates, in particular, interactions of the explicitly treated electrons with those that are excluded from the RECP calculations. The use of the effective Hamiltonian (8.55) instead of all-electron four-component Hamiltonians leads to the question about its accuracy. It was shown both theoretically and in calculations (see [498]) that the typical accuracy of the radially local RECPs is within $1,000\text{--}3,000\text{ cm}^{-1}$ for transition energies between low-lying states though otherwise is sometimes stated [465, 466].

In a series of papers [466, 498, 508, 509], a generalized RECP (GRECP) approach was developed that involves both radially local and separable Huzinaga-type potentials as its components. Additionally, the GRECP operator can include terms of other types, known as “self-consistent” and two-electron “term-splitting” corrections [498], which are important particularly for economical (but precise!) treatment of transition metals, lanthanides and actinides. With these terms, the accuracy provided by GRECPs can be even higher than the accuracy of the “frozen-core” approximation (employing the same number of explicitly treated electrons) because they can account for relaxation of explicitly excluded (inner-core) electrons [498]. In contrast to other RECP methods, GRECP employs the idea of separating the space around a heavy atom into three regions: inner core, outer core, and valence, which are first treated by employing different approximations for each. It allows one to attain practically any desired accuracy for compounds of lanthanides, actinides, and superheavy elements as well while requiring moderate computational efforts since the overall accuracy is limited in practice by possibilities of correlation methods.

8.3.3 *One-Center Restoration of Electronic Structure in the Core Region*

It should be noted that calculation of such properties as spin-dependent electronic densities near nuclei, hyperfine constants, chemical shifts, *etc.* with the help of the two-component pseudospinors smoothed in cores is impossible. However, the

above properties (and the majority of other “core-type” properties of practical interest that are described by the operators heavily concentrated within inner cores or on nuclei) are mainly determined by the electronic densities of the valence and outer-core shells near to, or on, nuclei. The valence shells can be open or easily perturbed by external fields, chemical bonding, *etc.*, whereas outer-core shells are noticeably polarized (relaxed) in contrast to the inner-core shells. Therefore, accurate calculation of electronic structure in the valence and outer-core region is of primary interest for such properties. The electronic densities evaluated from the two-component pseudowavefunction very accurately reproduce the corresponding all-electron four-component densities in the valence and outer-core regions not only for the state used in the RECP generation but also for other states that differ by excitations of valence electrons. In the inner-core region, the pseudospinors are smoothed, so that the electronic density with the pseudowavefunction is not correct. When operators describing properties of interest are heavily concentrated near or on nuclei, their mean values are strongly affected by the wavefunction in the inner region. The proper shapes of the valence four-component spinors must, therefore, be restored in atomic core regions after performing the RECP calculation. The applicability of the above two-step algorithm for calculation of wavefunctions of systems containing heavy atoms is a consequence of the fact that the valence and core electrons may be considered as two subsystems, interaction between which is described mainly by some integrated properties of these subsystems. The methods for consequent calculation of the valence and core parts of electronic structure give a way to combine the relative simplicity and accessibility both of RECP calculations in Gaussian basis set and of relativistic finite-difference one-center calculations inside a sphere with the atomic core radius. In 1959, a nonrelativistic procedure of restoration of the orbitals from smoothed Phillips–Kleinman pseudo-orbitals was proposed [457] based on the orthogonalization of the latter to the original atomic core orbitals. In 1985, Pacios and Christiansen [510] suggested a modified orthogonalization scheme in the case of shape-consistent pseudospinors. At the same time, a simple procedure of “nonvariational” one-center restoration (NOCR) employing the idea of generation of equivalent basis sets in four-component DHF and two-component RECP/SCF calculations was proposed by Titov and first applied in the calculations of the PbF molecule. Later, the two-step RECP/NOCR calculations of the hyperfine structure constants and other properties were performed for the XF molecules and radicals, X=Pb,Yb,Ba [511–515], the TlF [516] and PbO [517,518] molecules, and the molecular ion HI^+ [519]. In 1994, a similar procedure was used by Blöchl inside the augmentation regions [520] in solids to construct the transformation operator between pseudo-orbitals and original orbitals in his projector augmented-wave (PAW) method.

The NOCR scheme consists of the following steps [521]:

- Generation of *equivalent* basis sets

of one-center four-component spinors $\begin{pmatrix} f_{nlj}(r)\chi_{ljm} \\ g_{nlj}(r)\chi_{2j-l,jm} \end{pmatrix}$ and smoothed two-component pseudospinors $\tilde{f}_{nlj}(r)\chi_{ljm}$ in finite-difference all-electron

Dirac–Fock(–Breit) and RECP/SCF calculations of the same configurations of a considered atom and its ions. The χ_{ljm} is the two-component spin-angular function, and the $f_{nlj}(r)$ and $g_{nlj}(r)$ are the radial parts of the large and small components of Dirac spinors, respectively. The nucleus is usually modeled by a Fermi-charge distribution within a sphere. The all-electron four-component and two-component calculations are employed to generate two equivalent numerical basis sets used at the restoration. These sets, describing mainly the atomic core region, are generated independently of the basis set used for the RECP calculations.

- The molecular *pseudospinorbitals* from the RECP calculation are then expanded in the basis set of one-center two-component atomic *pseudospinors* (for $r \leq R_{\text{noct}}$, where R_{noct} is the radius of restoration that should be sufficiently large for calculating core properties with the required accuracy),

$$\tilde{\phi}_p(\mathbf{x}) \approx \sum_{l=0}^{L_{\max}} \sum_{j=|l-1/2|}^{|l+1/2|} \sum_{n,m} c_{nljm}^p \tilde{f}_{nlj}(r) \omega_{ljm}, \quad (8.57)$$

where $\mathbf{x}$ denotes spatial and spin variables.

- Finally, the atomic two-component pseudospinors in the basis set are replaced by equivalent four-component spinors, and the expansion coefficients from (8.57) are preserved:

$$\phi_p(\mathbf{x}) \approx \sum_{l=0}^{L_{\max}} \sum_{j=|l-1/2|}^{|l+1/2|} \sum_{n,m} c_{nljm}^p \begin{pmatrix} f_{nlj}(r) \omega_{ljm} \\ g_{nlj}(r) \omega_{2j-l,j,m} \end{pmatrix}. \quad (8.58)$$

The four-component spinors constructed in this way are orthogonal to the inner-core spinors of the atom, because the atomic basis functions used in (8.58) are generated with the inner-core shells treated as “frozen.”

8.3.4 Basis Sets for Relativistic Calculations of Molecules

The fully relativistic (four-component) LCAO calculations of molecular systems use contracted Gaussian-type spinors as the basis: two scalar wavefunctions within a two-component basis spinor are multiplied by a common expansion coefficient; for dimensions n of both the large and small components, the total number of variational parameters (the scalar expansion coefficients) is equal to $2n$ [480]. In the relativistic correlated calculations, the atomic basis sets should be optimized in the atomic correlated calculations. As Almlöf and Taylor showed [522], atomic basis sets optimized to describe correlations in atoms also describe correlation effects in molecules very well. The two main types of basis sets are used in correlation calculations of molecules: basis of atomic natural orbitals (ANO) suggested by

Almlöf and Taylor [522] and correlation-consistent (CC) basis set suggested by Dunning [448].

Atomic natural orbitals $\{\psi_p\}$ are obtained by unitary transformation of some set of orthonormal basis functions $\{\phi_p\}$. Natural orbitals diagonalize density matrix D_{ij} for some state (or group of the states) of the atom or its ions:

$$\rho(\mathbf{r}, \mathbf{r}') = \sum_{p,q} D_{pq} \phi_p^\dagger(\mathbf{r}) \phi_q(\mathbf{r}') = \sum_p n_p \psi_p^\dagger(\mathbf{r}) \psi_p(\mathbf{r}') \quad (8.59)$$

where n_p are *occupation numbers*. Only those $\{\psi_p\}$ are selected in the ANO basis set for which n_p is greater than some threshold: $n_p \geq n^{\text{thr}}$; $n^{\text{thr}} \sim 10^{-3} - 10^{-5}$.

Unlike the ANO scheme, the different numbers of primitive Gaussian functions are used in each basis set in the CC approach. Exponents of the polarization-correlation functions are optimized in correlation calculations of the atomic terms to provide the lowest possible total energy. It turns out that basis functions can be separated in groups and every function in each group lowers the total energy approximately by the same amount. Correlation consistency means that whole groups of functions are added to the basis set, not just separate functions.

Both ANO and CC schemes have a number of advantages, *that is*, the ANO basis set is relatively easy to construct and the smaller ANO basis is just a subset of the larger one. Advantages of the CC basis are the smaller number of the primitive functions and a natural criterion for estimation of the completeness of the basis set. The following disadvantages can be emphasized for CC and ANO basis sets:

- For *heavy atoms* with many electrons, the number of ANO and CC functions becomes too large to obtain satisfactory accuracy in transition energies and properties. Even for the light Ne atom, ANO basis sets obtained in correlation CI-SD calculation are [3s 2p 1d] with $n^{\text{thr}} \sim 10^{-3}$ and [5s 4p 3d 2f 1g] for $n^{\text{thr}} \sim 10^{-5}$.
- “Occupation number-optimized” (ANO) or “energy-optimized” (CC) basis sets do not take into account special features of one or another property and do not reflect properly the state of the “atom-in-molecule.”
- The incompleteness of atomic basis sets with the change of internuclear distance leads to basis-set superposition error (BSSE). This error is usually corrected by a “counterpoise” correction [523] that is calculated rather arbitrarily (it depends, in particular, on the atomic state used for its calculation) for ANO and CC basis sets.

The generalization of the correlation-consistent scheme of the basis-set generation was suggested (see [508] and references therein) which allows one to control effectively the quality of the basis set in different space regions depending on the property of interest. Practically all properties can be divided into two groups: (1) “valence” properties, which are determined by the wavefunction in the valence region, like dissociation energy or transition energies and (2) “core” properties, which are described by operators heavily concentrated near the nuclei of the heavy atom, like the hyperfine structure. The calculations of the different kinds of

properties require, in principle, different optimization criteria for basis sets. The generalized correlation (GC) basis set is constructed in the following stages:

1. Generation of the trial spin-orbitals, two-component spinors or four-component spinors in the atomic SCF calculation with *numerical functions*. Functions are obtained in SCF calculations of the atom and its ions; thus, trial functions are localized in valence or outer-core regions.
2. Criterion of choice of the optimal function is the *maximization* of some functional that depends on total energies of the states and transition energies between them. The energies of the states are obtained in some correlation calculation of the group of the states that describe an “atom-in-molecule” in the best way. The choice of the energetic functional is the key element of the GC-basis generation.
3. The resulting sets of functions are approximated by Gaussian functions with the same exponents for each l (or pair of lj) by the least square fit.

A commonly used choice of the functional is

$$\mathcal{F}_c(\Delta E_1, \dots, \Delta E_M) = \frac{1}{M} \sum_i^M \Delta E_i \quad (8.60)$$

Here, $\mathcal{F}_c$ is the change in the average energy for some considered group of the lowest-lying terms.

The functional used in the GC generation scheme can be chosen as follows:

$$\mathcal{F}_v(\Delta E_1, \dots, \Delta E_M) = \max_{i>j}^M |\Delta E_i - \Delta E_j| \quad (8.61)$$

where M is the number of atomic terms and $\Delta E_i \geq 0$ is the lowering of the total energy of the i th term in comparison to calculation without the given function. Thus, $\mathcal{F}_v$ presents the maximal change in transition energies. (Some other versions of the functional on changes of transition energies can also be used, but their results are not very different.)

Functional $\mathcal{F}_c$ is reasonable to use for generation of the GC basis for “core” properties, while $\mathcal{F}_v$ can be used when one is interested in “valence” properties. When only valence electrons are correlated, any functional can be used since the function giving the maximal change in total energy, as a rule, also provides the maximal change in transition energies in this case. In a universal scheme, both of the above functionals can be applied together when $\mathcal{F}_c$ is used in the first step to select the most important correlation functions and then $\mathcal{F}_v$ is used (see also [524] for a variational justification of the suggested functionals). If the effect of atomic polarization is important, the GC basis can be augmented by diffuse polarization functions, whose exponents are optimized in the SCF calculation of an atom in an electric field. The valence basis sets, used in relativistic molecular calculations, have to be in correspondence with RECP used in the basis set optimization. As was already mentioned, the basis sets corresponding to the “energy-consistent” RECP

can be found on the site www.theochem.uni-stuttgart.de. Highly accurate relativistic Gaussian basis sets are developed for the 103 elements from H to Lr [528]. Orbital exponents are optimized by minimizing the atomic self-consistent field (SCF) energy with the scalar-relativistic approximation. The basis sets are designed to have equal quality and to be appropriate for the incorporation of relativistic effects. The basis-set performance was tested by calculations on prototypical molecules, hydrides, and dimers of copper, silver, and gold using SCF and MP theory and the single- and double-coupled-cluster methods. Spectroscopic constants and dissociation energies are reported for the ground state of hydrides, which agree well with the experimental data (the mean absolute error relative to the experiment in dissociation energy, equilibrium bond length, and harmonic frequency is 0.09 eV, 0.003 Å, and 2 cm⁻¹, respectively). The optimized Slater-type basis sets for elements 1–118 are developed in [529]. The exponents of the Slater-type functions are optimized for the use in scalar-relativistic zero-order regular approximation (ZORA). These basis sets are used in DFT code ADF (<http://www.scm.com/Doc/Doc2006.01>) for calculations of molecules and solids. The use of RECP and valence basis sets for periodic systems is considered in the next section.

8.3.5 Relativistic LCAO Methods for Periodic Systems

The influence of relativistic effects on the structural and electronic properties of the crystals with heavy elements is well known [525].

One important effect is the strong relativistic contraction of *s* and *p* orbitals due to the nonnegligible probability to find them close to the nucleus; in turn, *d* and *f* orbitals are stretched due to indirect relativistic effects. This largely affects the interatomic distances, the cohesive energies, the one-electron energies, *etc.* This effect can be partly handled within the scalar-relativistic (SR) calculation, neglecting spin–orbit interaction. Another important relativistic effect is due to the spin–orbit coupling, which plays an essential role in the magnetic properties of solids [530]. The spin–orbit coupling requires more elaborate treatment beyond the SR calculations, *that is*, the two- or four-component relativistic calculations.

The four-component DHF–LCAO equations for 1D-, 2D-, and 3D-periodic systems were at first presented by Ladik [531]. The resulting somewhat complicated generalized matrix eigenvalue equation for solids is described (for details, we refer the reader to [531]). It was also shown for 1D and 2D systems how MP2 methods could be applied in their relativistic form. With the help of these, on the one hand, the total energy per unit cell (including correlation effects) can be computed. On the other hand, the relativistic band structure can also be corrected for correlation. Note that the symmetry of crystalline orbitals changes, compared with the nonrelativistic case, as the symmetry of the DHF Hamiltonian is described by double space groups. Finally, a scheme is proposed in which most of the electrons are treated in the standard way (Dirac–Hartree–Fock equations with only Coulomb interactions and calculation of all the other terms with the aid of

first-order perturbation theory), while for the core electrons of large- Z atoms or ions, the generalized relativistic HF equations are used. Therefore, one applies the solutions of the generalized relativistic HF equations for the construction of the relativistic Slater determinant in the case of core electrons, while for the rest of the electrons, the one-electron functions are obtained from the standard Dirac–Hartree–Fock equations. Unfortunately, the application of this fully relativistic theory (involving four-component spinors built in terms of a large and small component) is practically too difficult not only for solids but even for molecular systems (this application is limited to small-size molecules).

As was noted in the preceding sections, the relativistic calculations of molecular systems are made in quasirelativistic (two-component) approximations based on Hamiltonians operating on the large component only. Between different alternatives to decouple large and small components for molecules and solids, the Douglas–Kroll–Hess (DKS) approach [532, 533] is the most popular as this approach is variationally stable (and therefore can be incorporated into SCF calculations) and allows its accuracy to be improved [534]. In the DKS approach, the decoupling of large and small components of the Dirac Hamiltonian is made through a sequence of unitary transformations

$$H_m = U_m U_{m-1} \cdots U_1 U_0 H_D U_0^\dagger U_1^\dagger \cdots U_{m-1}^\dagger U_m^\dagger \quad (8.62)$$

Each transformation U_n is chosen in such a way that the offdiagonal blocks of the Dirac Hamiltonian are zero to a given order in the potential. The decoupled, block-diagonal transformed Hamiltonian

$$H_n = \begin{pmatrix} H_{\text{DKH}_n}^L & O(V^n) \\ O(V^n) & H_{\text{DKH}_n}^S \end{pmatrix} \quad (8.63)$$

The large-component block, $H_{\text{DKH}_n}^L$ is the two-component effective Hamiltonian to be included in the electronic-structure calculation. The order n of transformation can be systematically increased to improve the accuracy of transformation. Two classes of operators are involved in the construction of the DKH_n Hamiltonian: a function of the square of the momentum $f(P^2)$, $\mathbf{p} = -i\nabla$ and those involving the potential $V, (\boldsymbol{\sigma} \mathbf{p})V(\boldsymbol{\sigma} \mathbf{p})$, where $\boldsymbol{\sigma}$ are the Pauli spin matrices [534]. The explicit form of H_{DKH_n} up to fifth order was derived in [535, 536]. The DKH approach leads to a two-component formalism, which is separable in a spin-averaged (spin-free) and spin-dependent part. In the scalar-relativistic (SR) approximation, the spin-dependent part is ignored. The DKH transformation for the one-electron operators in scalar-relativistic HF–LCAO calculations with periodic boundary conditions is used in [537] and implemented in CRYSTAL88 code. The fact that scalar-relativistic effects are short range was made use of so that the electrostatic potential calculated by the Ewald method was not relativistically corrected. The results of SR–HF–LCAO calculations [537] of silver halides AgX ($\text{X}=\text{F}, \text{Cl}, \text{Br}$) with the fcc NaCl structure are presented in Table 8.6.

Table 8.6 Scalar-relativistic effects in AgX (X=F, Cl, Br) crystals [537]

Property	AgF	AgCl	AgBr	Ag
Lattice parameter (Å)	5.175 (5.191)	5.937 (5.990)	6.207 (6.260)	4.456 (4.546)
Binding energy (kJmol ⁻¹)	-371.2 (-407.5)	-385.9 (-417.7)	-333.4 (-362.8)	-53.0 (-39.4)
Bulk modulus (kbar)	459 (460)	306 (297)	273 (259)	298 (322)

Table 8.7 Crystal properties of fcc AgCl at various levels of theory [537]

Method	Total energy (a.u.)	Lattice const. (Å)	Binding energy (kJ mol ⁻¹)	Bulk modulus (kbar)
Nonrel. HF	-5656.601	5.990	-417.7	297
Rel. HF	-5771.344	5.937	-385.9	306
HF RECP	-159.709	5.943	-376.5	307
DFT ECP	-160.870	5.610	-514.6	560
Exper.	—	5.510	-519.8	535

The reoptimized uncontracted correlation corrected basis sets were used. The diffuse exponents (<0.04) in the basis set for Ag were discarded. The results given in Table 8.6 demonstrate the influence of scalar-relativistic effects in the AgX crystals properties (the results of nonrelativistic HF-LCAO calculations are given in brackets; the binding energy is given with reference to the HF ground-state energies of the free atoms). It is seen that lattice parameters show small relativistic effects—they decrease (up to 2% for Ag) as compared to the nonrelativistic values. The binding energies demonstrate a remarkable bond destabilization (up to 8.9% for AgF and 34.5% for Ag as compared to the nonrelativistic values). Bulk moduli change up to 7.5% (for Ag). Though scalar-relativistic effects of silver compounds are expected to be relatively small (compared with the compounds of heavier elements), remarkable changes of the HF binding energy and of the bulk modulus are observed. We note that in the relativistic HF calculations, the correlation effects are not included explicitly in the Hamiltonian (the correlation correction is included only in AO basis sets). In Table 8.7, properties of AgCl crystal are compared at various levels of theory. Table 8.7 demonstrates good agreement for the lattice parameter and bulk modulus between HF calculations with RECP (Hay-Wadt RECP is used) and the scalar (one-component)-relativistic HF-DKH approach. Slight differences are seen for the binding energy.

We noted that it is necessary to simultaneously include the relativistic and correlation effects in the Hamiltonian. Such inclusion for periodic systems is usually made in the relativistic DFT approaches.

The fully relativistic LCAO method for solids, based on the DKS scheme in the LDA approximation, was represented in [525]. The basis set consists of the numerical-type orbitals constructed by solving the DKS equations for atoms. This choice of basis set allows the spurious mixing of negative-energy states

known as variational collapse to be overcome. Furthermore, the basis functions transform smoothly to those in the nonrelativistic limit if one increases the speed of light gradually in a hypothetical way. This is also an important feature to avoid the variational collapse. The proposed approach was applied to Au and InSb crystals. The basis functions were chosen so that they have enough variational flexibility: not only were used AOs of neutral atoms but also those of positive ions Au^+ , Au^{2+} , Au^{3+} , In^{2+} , and Sb^{2+} . In the comparison for Au, the results of scalar- and two-component relativistic calculations (lattice constant and bulk modulus) indicate that the spin-orbit coupling plays a minor role in the structural properties of Au. The comparison of results of the relativistic calculations with those of the nonrelativistic calculations shows that the lattice constant is overestimated by 5% and the bulk modulus is underestimated by 35% in nonrelativistic calculations. This strongly shows the importance of the inclusion of the relativistic effects in the study of the structural properties of Au. In contrast with the case of Au, the results of nonrelativistic calculations of InSb are not so poor; the error in the lattice constant is 1%, and the error in the bulk modulus is 10%. This should be due to the fact that In and Sb are not so heavy that the relativistic effects do not play an important role in studying the structural properties of InSb.

The implementation of scalar relativity in an all-electron LDA linear combinations of the Gaussian-type orbitals (LCGTO) method for solids was reported by Boettger [526] and applied for crystalline Au with a fcc lattice. This initial implementation was later extended to include spin-orbit coupling terms, produced in the second-order DKH transformation. The GTO Au atomic basis set of $19s14p10d5f$ primitive GTOs was derived from scalar-relativistic (SR) and nonrelativistic (NR) calculations of paramagnetic atom. These calculations show that bulk and one-electron properties obtained by the LCGTO method are very close to those obtained with all-electron, scalar-relativistic DFT techniques using other basis sets (LAPW or LMTO SR methods). The efficiency of the LCGTO approximation in relativistic calculations of solids was demonstrated also in the calculations of equilibrium volumes and bulk moduli for the light actinides Th through Pu [539]. It is concluded that two independent (both scalar and quasirelativistic) electronic-structure DFT methods with the different choice of basis set (LCGTO and LAPW) are in good agreement with each other. Table 8.8 shows this agreement for fcc Th and Pu metals giving numerical values of the equilibrium volume V (a.u) and the bulk modulus B (GPa); for comparison, also results of FPLMTO calculations are given. The agreement between LCGTO and FPLAPW results is important, keeping in mind the primary advantage of LCAO methods over other existing DFT approaches (FLAPW, FLMTO)—*the possibility of LCAO methods to treat both molecular and periodic systems and in this way to bridge the gap between quantum chemistry and solid-state physics.*

Comparison of the nonrelativistic and scalar-relativistic results for fcc Au reveals the large impact that relativity has on the lattice constant (6%) and bulk modulus (57%) [526]. The most important qualitative change in the band structure of fcc Au is the more than 2-eV lowering of the s -band relative to the bottom of d -bands. In addition, the overall width of the d -bands is increased by more

Table 8.8 Equilibrium volume V (a.u.) and bulk modulus B (GPa) for Th and Pu with FPLMTO, LCGTO, and FPLAPW calculations, using DFT LDA and GGA Hamiltonians, with and without spin-orbit (SO) effects included [539]. Experimental data for fcc Th: $V=221.7$ a.u. and $B=58$ GPa

		fcc Th				fcc Pu			
		LDA	+SO	GGA	+SO	LDA	+SO	GGA	+SO
FPLMTO	V	—	182.1	—	199.9	109.2	—	119.2	—
	B	82.6	61.5	—	—	214	—	143	—
LCGTO	V	200.5	199.3	216.9	214.8	111.5	125.7	121.2	141.4
	B	64.8	71.7	58.8	63.4	218	124	170	97
FPLAPW	V	199.7	204.1	219.3	218.1	111.9	120.2	122.3	133.4
	B	61.0	78.6	56.7	73.1	194	143	153	121

than 15% due to a relativistic delocalization of the d states. The spin-orbit coupling including LCGTO DFT-GGA calculations was made for fluorite structure actinide oxides MO_2 ($\text{M}=\text{Th}, \text{U}, \text{Pu}$) and their clean and hydroxylated surfaces [540] magnetic ordering in fcc Pu [541] and bulk properties of fcc Pb [542].

In the calculations using nonrelativistic LCAO codes for solids, the relativistic effects are included implicitly in RECPs and basis sets. In the relativistic calculations of periodic systems, RECPs of the Stuttgart-Köln group (energy-consistent RECPs) are often applied. These RECPs (and the corresponding basis sets) are obtained in the relativistic DHF atomic calculations and are tabulated as the linear combination of GTFs; see www.theochem.uni-stuttgart.de. As was noted in Sect. 8.1, the basis sets generated for molecular calculations have to be adapted for the periodic system calculations. As an example, we mention the valence basis sets for lanthanide 4f-in-core relativistic pseudopotentials, adapted for crystal orbital *ab initio* calculations [543]. The crystalline calibration calculations were made for Ln_2O_3 ($\text{Ln}=\text{La}-\text{Pm}$) crystals with hexagonal space group $P\bar{3}m1$ and one formula unit per cell. The calibration within the HF and DFT schemes was made using the CRYSTAL03 code [21]. To verify these basis sets, the calculated geometries and cohesive energies were compared with experimental data. The valence basis sets adapted for crystal calculations restore the calculated cohesive energy of Ln_2O_3 ($\text{Ln} = \text{La}-\text{Nd}$) to more than 88% of the experimental data within the *a posteriori* HF correlation scheme in combination with gradient-corrected functionals. Good agreement has also been found between the conventional DFT results and the experimental cohesive energy with a deviation of only a few percent.

The implementation of the LCGTO relativistic two-component DKH approximation in a fully self-consistent all-electron DFT approach for molecules (this implementation requires changes to be made in the Hamiltonian [534]) allows the RECP results (when the nonrelativistic calculations are made with the use of relativistic pseudopotentials) to be compared with those obtained in scalar-relativistic and two-component relativistic calculations. Such a comparison was made in [544] for the bond-dissociation energy in the UF_6 molecule, obtained from the relative energies of the fragments ($\text{UF}_6 = \text{UF}_5 + \text{F}$), corrected for zero-point energy and spin-orbit interaction. The small-core RECP PBE0 and B3LYP

calculations give the bond-dissociation energy as 68.34 and 69.59 kcal/mole, respectively, all-electron two-component relativistic PBE0 and B3LYP calculations—the values 68.94 and 70.39 kcal/mole, while the experimental values are given between 69.5 and 73 kcal/mole. Note that the large-core RECP result is off by more than 50% so that to obtain a good agreement with experiment, one needs to work with a hybrid density functional and small-core RECP.

This conclusion was taken into account in RECP calculations of crystals. RECP hybrid DFT calculations were made for PtO crystal [407]. For Pt, 60 core electrons $[\text{Kr}]4d^{10}4f^{14}$ were replaced with the small-core relativistic Stuttgart–Dresden effective core potentials RECPs. A valence basis set was optimized for Pt considering $5s$, $5p$, $5d$, $6s$, and $6p$ orbitals. This basis set circumvents numerical linear dependencies in periodic calculations, and it is of similar quality to the Stuttgart basis set for most practical applications. Benchmark calculations in PtO using the 6-31G(d), the 6-311G(d), and 8-411G(d) basis sets for oxygen showed that these three bases yielded similar results. RECPs of the Stuttgart group were also applied in periodic hybrid DFT calculations of PuO_2 , Pu_2O_3 [408], PtN [406], and UO_2 [527].

The molecular calculations [534, 544] allow us to conclude that the DKH approximation in combination with hybrid DFT functionals provides a reliable tool for the prediction of structural and thermochemical properties of molecules.

The all-electron DFT LCAO approach with Gaussian basis sets was extended to scalar-relativistic calculations of periodic systems [545]. The approach is based on a third-order DKH approximation and, similar to the molecular case, requires only a modification of the one-electron Hamiltonian. The effective core Hamiltonian is obtained by applying the DKH transformation to the nuclear–electron potential V_N . Considering that relativistic effects are dominated by the short-range part of the Coulomb interaction, it is proposed to replace the nuclear–electron Coulomb operator used to build the DKH Hamiltonian by a short-range Coulomb operator

$$V^\zeta(\mathbf{r}) = -\frac{Z}{r} \text{erfc}(\zeta r) \quad (8.64)$$

where the complimentary error function screens the long-range tail of the potential. The use of the complimentary error function simplifies the calculation of the matrix elements between GTOs, but in general, any screening function could be employed. The correct nonrelativistic long-range behavior of the Coulomb operator is retained if the core Hamiltonian is defined as

$$H_{\text{core}} = H_{\text{DKHn}}^\zeta - V_N^\zeta + V_N \quad (8.65)$$

where the supraindex stands for quantities involving the short-range potential given by (8.64). The parameter ζ switches from a Hamiltonian where only the free-particle (averaged) kinetic energy is relativistically corrected ($\zeta \rightarrow \infty$), to the full-range DKHn Hamiltonian ($\zeta = 0$). In this way, the relativistic term $H_{\text{DKHn}}^\zeta - V_N^\zeta$ for periodic systems can be evaluated using V_N^ζ and $\mathbf{p}V_N^\zeta\mathbf{p}$ obtained by adding

contributions from a finite number of cells in direct space. It should be pointed out that the summation of V_N^ζ and $\mathbf{p}V_N^\zeta\mathbf{p}$ for $\zeta = 0$ diverges. The divergent term can be removed from the summation by adding a uniform charge-canceling background, as is usually done in Ewald-type summations. For the relativistic term $H_{\text{DKHn}}^\zeta - V_N^\zeta$, the contribution from the uniform background is exactly zero, since the DKH transformation does not change a uniform potential. The choice of ζ only affects the relativistic correction to the core Hamiltonian, while the nonrelativistic electrostatic contributions are entirely done using FMM; see Chap. 7. The tests on bulk systems by changing the value of ζ from 0.05 a.u. to 0.5 a.u. showed that the lattice constants, bulk moduli, and bandgaps are rather insensitive to ζ in this range [545] ($\zeta = 0.1$ has been chosen in the discussed calculations). In this approach, relativistic effects are included through the nucleus–electron interaction, while the electron–electron, Coulomb, the portion of Hartree–Fock exchange, and DFT exchange–correlation potential remain nonrelativistic. Such a strategy has been successfully employed for molecules and solids earlier.

The benchmark scalar-relativistic calculations [545] were made for the bulk metals (Pd, Ag, Pt, and Au) and the large bandgap semiconductors AgF and AgCl. It was shown that scalar-relativistic effects reduce the lattice constant by 0.06–0.10 Å for the 4*d* metals (Pd and Ag) and by 0.14–0.22 Å for the 5*d* metals (Pt and Au). For the 4*d* metals, scalar-relativistic effects increase the calculated bulk moduli by 20–40 GPa, while for the 5*d* metals, this increase is between 60 GPa and 100 GPa. For both AgF and AgCl crystals, scalar-relativistic effects decrease the energy gap—by 1.0 eV for AgF and 0.9 eV for AgCl.

The DKH approach allows relativistic all-electron DFT calculations to be performed using the traditional LDA and GGA approximations, as well as meta-GGA and hybrid density functionals. Slater-type basis sets were used in the relativistic DFT calculations, based on the ZORA Hamiltonian and applied for heavy metals and their surfaces [546, 547].

Concluding this chapter, we note that the relativistic correlated calculations of solids are mainly made in the DFT scheme. The post-DHF methods for solids wait their further development and implementation in computer codes for periodic systems.

In the next five chapters, we illustrate the possibilities of LCAO methods in the calculations of different crystalline-solid properties for pure and defective 3D (bulk) crystals, 2D surfaces, and monopерiodic (1D) nanotubes. We refer the reader to the very informative review article [552], where it is possible to find many illustrations of *ab initio* simulation possibilities in the area of solid-state chemistry, physics, materials and surface science, and catalysis. This publication is especially useful as an introductory overview for the reader who is not acquainted with solid-state simulation. All the examples discussed in [552] have been generated with the CRYSTAL code and implemented by the authors and collaborators. CRYSTAL was the first periodic *ab initio* code to be distributed to the scientific community beginning in 1989. Now, several *ab initio* LCAO codes are available to users (see Appendix C), but the CRYSTAL code remains the most user-friendly and fast-developing code being applied now in more than 250 research groups in the world.

We do not discuss here the electron–phonon and isotope effects on the optical spectra of solids. In [548, 549], these effects were studied in the framework of the tight-binding (TB) LCAO approach for several semiconductors with diamond and zincblende structure. The results reproduce the overall trend of the available experimental data for the bandgap as a function of temperature, as well as give correctly the mass dependence of the bandgap.

The TB approach represents a conceptual bridge between *ab initio* simulations and model-potential ones. In particular, the coupling of TB with the molecular dynamics (MD) generates the TBMD method as a valuable tool for atomic-scale materials modeling [550]. A description of the TB method can be found, for example, in [6, 551].

Chapter 9

LCAO Calculations of Perfect-Crystal Properties

In this chapter perfect-crystal properties are considered: the analysis of chemical bonding on the basis of the population analysis; the one-electron properties and properties, defined by the total energy and its derivatives; and the magnetic ordering in crystals. We demonstrate that the use of hybrid exchange-correlation functional allows reproducing the equilibrium volumes and structural, electronic, dielectric, and vibrational properties of paraelectric cubic and three ferroelectric (tetragonal, rhombohedral, and orthorhombic) BaTiO_3 phases in good agreement with the existing experimental data. It is also shown that the use of the first-principles LCAO approach allows BaTiO_3 thermodynamic properties calculation, providing valuable information on the low-temperature behavior that is not easy to obtain by experimental techniques. The efficiency of the LCAO method in the quantum mechanics–molecular dynamics approach to the interpretation of X-ray absorption is illustrated using perovskite and ReO_3 examples.

9.1 Theoretical Analysis of Chemical Bonding in Crystals

9.1.1 Local Properties of Electronic Structure in LCAO HF and DFT Methods for Crystals and Post-HF Methods for Molecules

Crystals, like molecules, are made up of atoms interacting with one another, which gives rise to electron-density localization along bonds (covalent solids), around atomic nuclei (ionic crystals), or to the more complex and most widespread pattern of electron-density distribution. Considered in Chap. 4, the density matrix of molecules and crystals in the LCAO approximation permits one to derive the local characteristics of the electronic structure employed usually when describing chemical bonding in molecules or crystals (the electronic configuration of an

atom, atomic charges Q_A , atomic bond orders W_{AB} and covalency C_A , and total and free atomic valences). In molecular quantum chemistry such calculations are known as population analysis. In molecular theory the local electronic-structure characteristics were introduced at first for the orthogonal atomic basis used in semiempirical ZDO calculations (see Chap. 6), with subsequent generalization to the case of a nonorthogonal basis employed in nonempirical HF and DFT calculations [91, 553, 554]. The first attempts at a theoretical determination of local electronic-structure characteristics of periodic systems were made later: for the orthogonal basis set used in semiempirical versions of the HF method in [555, 556] and for the nonorthogonal AO basis—in [557, 558]. Note that determination of local characteristics of electronic structure by traditional methods of solid-state physics, which make use, as a rule, of the plane-wave basis, requires special projection techniques (see Sect. 9.1.5), involving additional approximations to calculate electron-density-matrix elements in an atomic basis.

The local properties of the electronic structure of a periodic system are defined by the density matrix $\rho(\mathbf{R}, \mathbf{R}')$ (see (4.91)); the electron position vectors $\mathbf{R}$ and $\mathbf{R}'$ vary within the basic domain of a crystal consisting of N primitive unit cells. For a one-determinant wavefunction, the density matrix can be expressed through Bloch-type spin-orbitals $\psi_{ik}^\sigma(\mathbf{R})(\sigma = \alpha, \beta)$:

$$\rho(\mathbf{R}, \mathbf{R}') = \rho^\alpha(\mathbf{R}, \mathbf{R}') + \rho^\beta(\mathbf{R}, \mathbf{R}') = \sum_{\sigma} \sum_i^{\text{occ}} \sum_k \psi_{ik}^\sigma(\mathbf{R}) \psi_{ik}^{\sigma*}(\mathbf{R}') \quad (9.1)$$

In the LCAO approximation,

$$\psi_{ik}^\sigma(\mathbf{R}) = \sum_{\mu} C_{i\mu k}^\sigma \chi_{\mu k}(\mathbf{R}) \quad (9.2)$$

$$\chi_{\mu k}(\mathbf{R}) = \frac{1}{\sqrt{N}} \sum_n \exp(i\mathbf{k} \mathbf{R}_n) \chi_{\mu}(\mathbf{R} - \mathbf{R}_A - \mathbf{R}_n) \quad (9.3)$$

where $\chi_{\mu}(\mathbf{R} - \mathbf{R}_A - \mathbf{R}_n) = \chi_{\mu}^{An}(\mathbf{R})$ is the atomic orbital centered on atom A in the primitive unit cell with a translation vector $\mathbf{R}_n$. In the basis of Bloch sums $\chi_{\mu k}(\mathbf{R})$, the overlap matrix $S_{\mu\nu}(\mathbf{k})$ and density matrix $P_{\mu\nu}(\mathbf{k})$ are introduced:

$$S_{\mu\nu}(\mathbf{k}) = \sum_n \exp(i\mathbf{k} \mathbf{R}_n) \int \chi_{\mu}^*(\mathbf{R} - \mathbf{R}_A) \chi_{\nu}(\mathbf{R} - \mathbf{R}_B - \mathbf{R}_n) d\mathbf{R} \quad (9.4)$$

$$P_{\mu\nu}^\sigma(\mathbf{k}) = \sum_i^{\text{occ}} C_{i\mu k}^{\sigma*} C_{i\nu k}^\sigma \quad (9.5)$$

The expansion coefficients $C_{i\mu k}^\sigma$ are calculated by solving the matrix equation of the CO LCAO method for crystals (see (4.67)):

$$F^\sigma(\mathbf{k}) C^\sigma(\mathbf{k}) = S(\mathbf{k}) C^\sigma(\mathbf{k}) E^\sigma(\mathbf{k}) \quad (9.6)$$

In (9.6) $F^\sigma(\mathbf{k})$ is the matrix of the Hartree–Fock (HF) or Kohn–Sham (KS) operator. The former operator includes a nonlocal exchange part, depending on the density

matrix $\rho(\mathbf{R}, \mathbf{R}')$, whereas the latter operator involves the electron density $\rho(\mathbf{R}) = \rho(\mathbf{R}, \mathbf{R})$, that is, it depends only on the diagonal elements of the density matrix; see Chaps. 4 and 7.

In view of the translational symmetry of a crystal, one can introduce density normalization per primitive unit cell containing n electrons:

$$Sp(PS) = \frac{1}{N} \sum_{\mathbf{k}} \sum_{\mu} [P(\mathbf{k})S(\mathbf{k})]_{\mu\mu} = \sum_{\mu} (PS)_{\mu\mu}^{A0,A0} = n \quad (9.7)$$

The Mulliken population analysis may be extended to crystalline solids [557, 558, 560], giving the following definitions for an electronic population N_{A0} on an atom, atomic charge Q_{A0} , bond order $W_{A0,Bn}$, covalency C_{A0} , and the total valency V_{A0} ($A0, Bn$ mean atom A in the reference unit cell and atom B in the unit cell with a translation vector $\mathbf{R}_n$):

$$N_{A0} = \sum_{\mu \in A0} P_{\mu\mu}^{A0,A0} + \sum_{B \notin A0} R_{A0,B0} + \sum_{n \neq 0} \sum_B R_{A0,Bn} \quad (9.8)$$

where the overlap population is defined as

$$R_{A0,Bn} = \sum_{\mu \in A0} \sum_{v \in Bn} P_{\mu v}^{A0,Bn} S_{v\mu}^{Bn,A0} \quad (9.9)$$

and the atomic charge as

$$Q_{A0} = Z_{A0} - N_{A0} \quad (9.10)$$

In (9.10) Z_{A0} is the nuclear charge for the all-electron calculation or the core charge if the pseudopotential approximation is used. The bond order and covalency are

$$W_{A0,B0} = \sum_{\mu \in A0} \sum_{v \in Bn} \left[(PS)_{\mu v}^{A0,Bn} (PS)_{v\mu}^{Bn,A0} + (P^s S)_{\mu v}^{A0,Bn} (P^s S)_{v\mu}^{Bn,A0} \right] \quad (9.11)$$

$$C_{A0} = \sum_{B \neq A0} W_{A0,B0} + \sum_{n \neq 0} \sum_{Bn} W_{A0,Bn} = 2N_{A0} - W_{A0,A0} \quad (9.12)$$

In (9.11), $P = P^\alpha + P^\beta$ and $P^s = P^\alpha - P^\beta$. In deriving (9.12), the idempotency relation for the density matrix in the nonorthogonal AO basis $(PS)^2 = 2(PS) - (P^s S)^2$ was used (see (4.130)). Equations (9.11) and (9.12) are applied in unrestricted HF (UHF) or spin-polarized (SP)KS calculations. For the closed-shell case (RHF and KS calculations), $P^\alpha = P^\beta$ and $P^s = 0$.

The definition of the total valency of the atom accounting for both the ionic (electrovalence) and covalent (covalence) components of chemical bonding was suggested in [555] for molecular systems and extended to crystalline solids in [556]. The atomic total valence is of the form

$$V_{A0} = \frac{1}{2} \left(C_{A0} + \sqrt{C_{A0}^2 + 4Q_{A0}^2} \right) \quad (9.13)$$

To study the influence of the correlation effects on the local properties of electronic structure, DFT or post-HF methods can be used. If the KS equations are solved, the definitions (9.8)–(9.13) of local properties include the correlated density matrix and therefore take into account the correlation effects.

We note that there are no rigorous quantum-mechanical definitions for the local characteristics of the electronic structure. The definitions given above require the LCAO approximation, and the numerical results depend on the choice of atomic basis. In attempting to separate an atomic subsystem or a molecular subsystem in systems with a strong coupling, we should refuse to describe this subsystem by using pure states, which leads to considerable conceptual and computational problems. For example, an atomic subsystem in a molecular system, as a rule, cannot be assigned a certain integral number of the electrons involved (the calculated atomic electronic population (9.8) is noninteger), which implies that this subsystem should be represented by an ensemble of states matched by different numbers of electrons. However, an approach exists that gets around the above difficulties. This approach rests on the analysis of reduced density matrices (as a rule, these are the first-order and second-order matrices) of a system as a whole, and the separation of a particular subsystem is generally based on some geometric criteria. This makes it possible to considerably simplify computations but leads to some arbitrariness in the choice of the definitions for local characteristics of the electronic structure.

This arbitrariness most clearly manifests itself in going beyond the scope of the HF approximation, as evidenced by a wide variety of definitions for molecular systems available in the literature for valences and bond orders in the case of post-Hartree–Fock methods for molecular systems [554, 562–564]. In post-HF methods, local characteristics of molecular electronic structure are usually defined in terms of the first-order density matrix, and in this sense, there is no conceptual difference between HF and post-HF approaches [561]. It is convenient to introduce natural (molecular) spin-orbitals (NSOs), *that is*, those that diagonalize the one-particle density matrix. The first-order density matrix in the most general case represents some ensemble of one-electron states described by NSOs

$$\rho = \sum_{i=1}^{2n} \lambda_i |\psi_i\rangle \langle \psi_i| \quad (9.14)$$

where λ_i are the NSO occupation numbers so that $\sum_{i=1}^{2n} \lambda_i = N$, $\lambda_i \geq 0$ for all $i = 1, 2, \dots, 2n$ and the characteristic feature of the HF case is that exactly N weights λ_i in this expansion are equal to 1 (due to the normalization condition, the remaining $(2n - N)$ should be equal to 0). Here, N is the total number of electrons. In geometric terms, this property of the HF density matrix means that it is a projector on the subspace of occupied NSO or, equivalently, that the N -electron

state is described by a single-determinant wavefunction. In any post-HF method, based on the wavefunction formalism, the coefficients in expansion (9.14) satisfy the representability conditions: $0 \leq \lambda_i \leq 1$. Some of these coefficients can be close to 1 (strongly occupied NSO) and some close to 0 (weakly occupied NSO), but in any case, the post-HF density matrix loses its property $\rho^2 = \rho$. Turning to the basis of natural orbitals (NOs) results in the appearance of two spin components of the density matrix, ρ^α and ρ^β . For RHF, ROHF, and UHF cases, these spin components are idempotent, being projectors on the subspace of the full MO space spanned by the occupied σ -MOs ($\sigma = \alpha, \beta$). The density operator is the Hermitian positive-semidefinite operator with a spur equal to the number of electrons. At the same time, in general, this operator does not possess any other specific properties, for example, idempotency. After the convolution over the spin variables, the density operator breaks down into two components whose matrix representation in the basis set of atomic orbitals (AOs) has the form

$$\hat{\rho}^\sigma \chi_\mu = \sum_{\nu=1}^n \chi_\nu (P^\sigma S)_{\nu\mu} \quad (9.15)$$

where S is the AO overlap matrix and the matrix elements of the P^σ matrix are related to the occupation numbers and the coefficients $C_{i\mu}^\sigma$ in the expansion of the spatial parts of natural spin orbitals in the AO basis set through the expressions

$$P_{\mu\nu}^\sigma = \sum_{i=1}^n C_{i\mu}^\sigma \lambda_i^\sigma (C_{\nu i}^\sigma)^* \quad (9.16)$$

In principle, it is not difficult to define the σ -occupancy of the atomic subspace (subspace spanned by AOs of atom A). To this end it is sufficient to calculate

$$N_A^\sigma = Sp [\hat{\rho}^\sigma \hat{\rho}_A] \quad (9.17)$$

where $\hat{\rho}_A$ is the projector on the subspace of atom A. This value gives us a certain measure of immersion of atom A subspace into the subspace of σ -occupied NOs. Such a definition, however, is not satisfactory because due to the nonorthogonality of the AO basis, the sum of occupancies will be greater than the total number of electrons. A reasonable approach consists of turning to the so-called biorthogonal basis $\tilde{\chi}_\mu$ and introducing the atomic projector as

$$\hat{\rho}_A = \sum_{\mu \in A} |\chi_\mu\rangle \langle \tilde{\chi}_\mu| \quad (9.18)$$

where $\tilde{\chi} = \chi S^{-1}$ and $\langle \chi_\mu | \tilde{\chi}_\mu \rangle = \delta_{\mu\nu}$. Operator (9.18) is idempotent and Hermitian.

Let the atomic basis set be well localized on atoms (or the atomic fragments under consideration) and be orthonormal. The unit operator can be expanded as

$$\hat{I} = \sum_A \hat{\rho}_A \quad (9.19)$$

This operator has a unit matrix with respect to the AO basis set and can be used as the right identity in manipulations in AO basis. In particular,

$$Sp \hat{\rho}^\sigma = \sum_A Sp \hat{\rho}^\sigma \hat{\rho}_A = N^\sigma \quad (9.20)$$

With such definitions, the total electron occupancy of atom A is calculated as

$$N_A = N_A^\alpha + N_A^\beta = \sum_\sigma Sp \hat{\rho}^\sigma \hat{\rho}_A = \sum_\sigma \sum_{\mu \in A} (P^\sigma S)_{\mu\mu} \quad (9.21)$$

In order to determine the two-center bond order, it is reasonable to attempt to obtain the expansion similar to (9.20) but for the squares of the density-operator components. Unfortunately, in the general case, the spur of the density operator squared $Sp(\hat{\rho}^2) = \sum_\sigma Sp(\hat{\rho}^\sigma)^2$ depends on both the AO basis set and the computational technique and can be treated as a certain characteristic of a system only with the very large basis sets and full configuration interaction. Furthermore, even in this limiting case, the physical meaning of the given characteristic is not quite clear. However, instead of the σ -components of the density operator, it is possible to consider their combinations $\hat{\rho}^{\alpha+\beta} = \hat{\rho}^\alpha + \hat{\rho}^\beta$ and $\hat{\rho}^{\alpha-\beta} = \hat{\rho}^\alpha - \hat{\rho}^\beta$ that are referred to as the total electron and spin-density operators, respectively, and to examine the contributions to the squares of these operators. Both approaches are consistent with each other and with the standard analysis within the Hartree–Fock approximation for occupied shells when one uses the expansion of the doubled sum of the density-operator σ -components squared

$$\sum_\sigma Sp (\hat{\rho}^\sigma)^2 = \sum_\sigma \sum_{A,B} Sp \hat{\rho}^\sigma \hat{\rho}_A \hat{\rho}^\sigma \hat{\rho}_B = \sum_\sigma \sum_{A,B} \sum_{\mu \in A, \nu \in B} (P^\sigma S)_{\mu\nu} (P^\sigma S)_{\nu\mu} \quad (9.22)$$

The quantities

$$W_{AB} = 2 \sum_\sigma \sum_{\mu \in A, \nu \in B} (P^\sigma S)_{\mu\nu} (P^\sigma S)_{\nu\mu} \quad (9.23)$$

at $B \neq A$ can be interpreted as certain characteristics of bond $A - B$ order. Their sum

$$C_A = \sum_{B \neq A} W_{AB} \quad (9.24)$$

may be treated as the covalence of A atom. The one-center terms $F_A = W_{AA}$ in (9.23) are termed the free (nonrealized) valence of atom A .

The results obtained in post-HF methods for solids refer mainly to the energy of the ground state but do not provide the correlated density matrix. The latter

is calculated for solids in the one-determinant approximation. The density matrix calculated for crystals in RHF or ROHF one-determinant methods describes the many-electron state with the fixed total spin (zero in RHF or defined by the maximal possible spin projection in ROHF). Meanwhile, the UHF one-determinant approximation formally corresponds to the mixture of many-electron states with the different total spin allowed for the fixed total spin projection. Therefore, one can expect that the UHF approach partly takes into account the electron correlation. In particular, of interest is the question to what extent UHF method may account for correlation effects on the chemical bonding in transition-metal oxides. An answer to this question can be obtained in the framework of the *molecular-crystalline approach*, proposed in [561] to evaluate the correlation corrections in the study of chemical bonding in crystals.

Conceptually, the method is as follows. The local characteristics of a crystal electronic structure are calculated within the periodic model by the Hartree–Fock method to choose the molecular cluster that adequately describes the local features of the electronic structure. In the majority of cases, the number of atoms comprising this cluster is appreciably less than the number of atoms contained in the clusters simulating one-electron states in a crystal. At the next stage of the advanced approach, the chosen cluster is calculated in the framework of the multiconfigurational approximation using the molecular programs providing the expansion of wavefunctions into determinants. Then, by applying the UHF method to the calculations of the cluster and the crystal, one can obtain the one-determinant solutions, which correspond to the generalized valence bonds. Simple rearrangements of the multiconfigurational cluster function permit one to explicitly separate the obtained valence bonds in its expansion. If these valence bonds turn out to be dominant in the expansion, then, in order to construct the many-electron function of a crystal, it is sufficient to replace the cluster valence bonds by the crystal valence bonds. Thus, the constructed wavefunction explicitly includes the electron correlation effects. By convoluting the many-particle density matrix into two- and one-particle density matrices, it is possible to calculate the local characteristics of chemical bonding in a crystal by the known formulas.

In Sect. 9.1.4, we discuss the results of such an approach for application to the Ti_2O_3 crystal with the open-shell configuration d^1 of the Ti^{3+} ion. It is common knowledge that the electron correlation can play an important role in compounds of transition metals with an unfilled d electronic shell. The density-functional method (LDA or GGA), which has been widely employed for these crystals, often appears to be unsatisfactory because of an incorrect description of the self-interaction (see Chap. 7).

9.1.2 Chemical Bonding in Cyclic-Cluster Model: Local Properties of Composite Crystalline Oxides

The above formalism for calculation of local electronic-structure characteristics of crystals was at first applied in the cyclic-cluster CNDO semiempirical calculations

[555] of composite crystalline oxides with the metal atom oxidized to various degrees. In chemistry the oxidation state is a measure of the degree of oxidation of an atom in a chemical compound. It is the hypothetical charge that an atom would have if all bonds to atoms of different elements were 100% ionic. Metal oxidation states are positive and denoted by I, II, and III for oxidation states one, two, and three, respectively. It should be remembered that the oxidation state of an atom does not represent the “real” charge on that atom: this is particularly true of high oxidation states, where the ionization energies required to produce a multiply positive ion are far greater than the energies available in chemical reactions. The assignment of electrons between atoms in calculating an oxidation state is purely a formalism, albeit a useful one for the understanding of many chemical reactions. It was shown [296] that it is the full atomic valence (9.13) that correlates and in many cases is numerically close to the oxidation state. Usually, composite oxides of heavy-metal atoms crystallize in structures with low-symmetry space groups and contain many atoms in their unit cell. Due to the large atomic (or ionic) radii of the metallic atoms, these compounds have both nontypical metal–oxygen bond lengths and atomic coordination numbers. As a rule, the constituent heavy-metal elements exhibit a different oxidation state. The variable valence of the metal atoms makes the formation of oxides with different chemical compositions (simple, composite, and miscellaneous oxides) possible. The simple oxides contain metal atoms with constant valence (e.g., Cu_2O , La_2O_3). However, in miscellaneous oxides, the metal atoms of the same chemical elements occur in the different oxidation states (e.g., Fe_3O_4 , Cu_4O_3). The heavy-metal oxides may lose or acquire oxygen atoms forming a defective crystalline structure and nonstoichiometric compounds.

Unlike light-metal oxides, the investigation of the electronic structure of crystalline heavy-metal oxides is a difficult task because of their composite crystal structure. Thus, it is necessary to use approximations both for the crystal-structure description and for the choice of one-electron Hamiltonian.

It is necessary to investigate the electronic structure of defect-containing metal oxides to understand their physical and chemical properties. However, the first step of such an investigation is connected with the calculation of the electronic structure of perfect nondefective crystal. The analysis of ionic and covalent components of the chemical bonding in perfect crystal allows one to propose realistic models describing the defects in these compounds.

The calculations of local properties of metal-oxide electronic structure [555, 565–567] were made in the cyclic-cluster model, in the CNDO approximation. As in the CNDO approximation, AOs that are supposed to be orthogonalized by the Löwdin procedure (see Chap. 6), the definitions of local properties given in Sect. 9.1.2 for nonorthogonal basis, have to be modified. In particular, the overlap population (9.9) becomes zero in the CNDO approximation, so that the electronic population is defined only by diagonal density-matrix elements $P_{\mu\mu}^{A0,A0}$. In (9.6) and in the bond-order definition (9.11) the overlap matrix has to be replaced by an identity matrix. The matrix elements of the cyclic-cluster Hamiltonian are given by (6.61), (6.62) and depend on the semiempirical one-center parameters β_M , $U_{\mu\mu}$, γ_{MM} and two-center Coulomb integrals γ_{MN} . The one-center parameters for the light elements

Table 9.1 CNDO semiempirical parameters of atoms used in crystalline metal oxides calculations (in eV)

Element	γ_{MM}	U_{ss}	U_{pp}	U_{dd}	β_M
Li	3.47	−4.99			−1.8
O	13.63	−101.31	−84.287		−17.0
K	3.70	−4.15			−1.8
Cu	17.20	−162.23		−171.46	−8.4, −14.6
Sr	3.75	−9.43			−1.8
Y	8.50	−20.80		−22.80	−5.8
Ba	4.20	−10.30			−1.8
La	7.30	−15.08		−19.08	−5.0
Pb	4.30	−26.30	−21.500		−7.7
Ni	17.00	−140.90		−149.00	−5.0, −10.0

with s and p valence electrons have been taken from [568], where these parameters were calibrated for molecular calculations. The one-center parameters for copper, lead, nickel, and lanthanum atoms were calibrated so that the results of the electronic-structure calculations correlate well with the experimental data for the simple oxides of these elements. The Coulomb integrals γ_{MN} were estimated from the one-center γ_{MM} and γ_{NN} Coulomb integrals using Ohno's approximation [229]. The numerical values of the bonding parameters β_{MN} are connected with the choice of the atomic basis functions. As the double-zeta atomic functions of the neutral atoms were used, the bonding parameters β_M for the light elements were recalibrated as their values in [568] correspond to Slater single-zeta atomic functions. The bonding parameter β_{MN} was taken to be equal to $\sqrt{\beta_{MM}\beta_{NN}}$ as is done in many molecular calculations. The numerical values of CNDO parameters of atoms are given in Table 9.1. The details of their choice for actual atoms can be found in [555]. The crystal structures of the considered composite metal oxides are given in Table 9.2 (the references to the corresponding experimental data can be found in [555]). The calculated atomic charges and full atomic valences are given in Table 9.3 for nonequivalent (not connected by the symmetry transformations) atoms, both with variable valence (Cu,Pb,Ni) and constant valence (oxygen and metal atoms Me in different oxidation states).

For comparison the crystallographic valences in copper–oxide compounds, calculated for the experimental bond lengths, are given in brackets.

The crystallographic valence (CV) of the i th atom in a crystal is defined as the sum

$$\tilde{V}_i = \sum_j B_{ij} \quad (9.25)$$

where the summation is performed over all the atoms with charge opposite in sign to that of the i th atom and B_{ij} is the so-called bond valence of the i th and j th atoms. It has been found that in acid-base networks, the bond valence B_{ij} correlates well with

Table 9.2 The crystal structure of metal oxides

Compound	Space group	Z	Cu,Pb,Ni	Me	O
Cu ₂ O	$Pm\bar{3}m$	2	4b		2a
YCuO ₂	$R\bar{3}m$	3	3a	3b	6c
LaCuO ₂	$R\bar{3}m$	3	3a	3b	6c
CuO	$C2/c$	4	4c	4e	
NiO	$R\bar{3}m$	3	3a		3b
Cu ₄ O ₃	$I4_1/adm$	4	8c,8d		4a,8e
Li ₂ CuO ₂	$Immm$	2	2b	4j	4i
SrCuO ₂	$Cmcm$	4	4c	4c	4c,4c
Sr ₂ CuO ₃	$Immm$	2	2d	4f	2a,4f
MgCu ₂ O ₃	$Pmmm$	2	4e	2a	2b,4e
Y ₂ Cu ₂ O ₅	$Pn2_1a$	4	4a,4a	4a,4a	4a,4a,4a,4a,4a
NaCuO ₂	$P\bar{1}$	1	1a	1h	2i
KCuO ₂	$Cmcm$	4	4c	4c	8f
LaCuO ₃	$R\bar{3}c$	6	6b	6a	18e
La ₂ O ₃	$P\bar{3}m1$	3		6d	3a,6d
La ₂ CuO ₄ orth	$Cmca$	4	4a	8f	8e,8f
La ₂ NiO ₄ orth					
La ₂ CuO ₄ tetr	$I4/mmm$	1	1a	2e	2c,2e
La ₂ NiO ₄ tetr					
YBa ₂ Cu ₃ O ₆	$P4/mmm$	1	1a,2g	Y:1d Ba:2h	4i,2g
YBa ₂ Cu ₃ O ₇	$Pmmm$	1	1a,2q	Y:1h Ba:2t	1e,2s,2r,2q
α -PbO	$P4/mnm$	2	2c		2a
β -PbO	$Pbcm$	4	4d		4d
α -PbO ₂	$Pbcn$	2	4c		8d
β -PbO ₂	$P4/mnm$	4	2a		4f
Pb ₂ O ₃	$P2_1/a$	4	4e,4e		4e,4e,4e
Pb ₃ O ₄	$P4_2/mbc$	4	4d,8h		8g,8h

Z is the number of formula units in the unit cell

the bond length R_{ij} and can be approximated by the inverse power or logarithmic function

$$B_{ij} = (R_{ij}/R_0)^{-N} \quad (9.26)$$

$$B_{ij} = \exp \left[-\frac{R_{ij} - R_0}{B} \right] \quad (9.27)$$

The fitted constants N , R_0 and B depend only on the nature of the bonded atoms (i, j) and are given in the literature [569, 570] or may be calculated by the computer code VALENCE [571] designed to calculate bond valences from bond lengths and *vice versa*. This code allows also calculation of bond-valence sums and average bond lengths, and can determine bond-valence parameters from the bonding environments of different cations.

Table 9.3 Atomic charges and full atomic valences in crystalline metal oxides^a

Crystal	Atomic charges				Full atomic valences			
	Cu, Pb, Ni	O1	O2	Me	Cu, Pb, Ni	O1	O2	Me
Cu ₂ O	0.97	−1.94			1.03 (1.29)	2.00 (2.58)		
YCuO ₂	0.99	−1.59		2.18	1.08	2.03		3.06
LaCuO ₂	0.97	−1.73		2.49	1.02 (1.25)	2.01 (2.16)		3.03 (3.07)
CuO	1.60	−1.60			2.18 (2.04)	2.01 (2.04)		
NiO	1.87	−1.87			2.00	2.00		
Cu ₄ O ₃	0.96 1.57	−1.72	−1.56		1.02 2.11 (1.25) (1.99)	2.00 2.01 (2.15) (2.17)		
Li ₂ CuO ₂	1.43	−1.71		0.99	1.92 (1.84)	1.99 (1.99)		1.00
SrCuO ₂	1.43	−1.60	−1.74	1.90	1.98 (2.01)	1.99 2.00 (2.08) (1.80)	1.99	1.99 (1.87)
Sr ₂ CuO ₃	1.38	−1.84		1.99	1.81 (1.90)	1.99 1.97 (1.82) (2.16)	2.00	2.00 (1.96)
MgCu ₂ O ₃	1.31	−1.49		1.98	1.72	2.01 1.98	2.00	
Y ₂ Cu ₂ O ₅	1.59 1.67	−1.20 −1.58 −1.18	−1.32 −1.32	1.68 1.67	2.25 2.29	2.09 2.06 2.02 2.06 2.10	3.13 3.14	
NaCuO ₂	1.89	−1.44		0.99	2.56 (2.52)	2.01 (1.91)		1.00 (1.29)
KCuO ₂	2.08	−1.54		0.99	2.73 (2.50)	2.00 (1.73)		1.00 (0.95)
LaCuO ₃	2.19	−1.54		2.45	2.82 (2.96)	2.02 (1.90)		3.02 (2.75)
La ₂ O ₃		−1.68, −1.60		2.43		2.01 2.03	3.03	
La ₂ CuO ₄ orth	1.56	−1.52, −1.54		2.28	2.18 (2.38)	2.00 (2.19)	1.98 (1.67)	3.01 (2.67)
La ₂ NiO ₄ orth	1.86	−1.76, −1.65		2.45	2.01	2.00		3.00
La ₂ CuO ₄ tetr	1.70	−1.61, −1.63		2.39	2.38 (2.45)	2.01 (2.28)	1.98 (1.46)	3.00 (2.52)
La ₂ NiO ₄ tetr	1.88	−1.76, −1.67		2.48	2.01	2.00		3.00
YBa ₂ Cu ₃ O ₆								
Cu–O chains	0.97	−1.97		Y:2.44	1.00 (1.42)	2.00 (1.94)		3.03 (2.89)
Cu–O planes	1.57	−1.65			2.12 (2.12)	2.01 (2.13)		
YBa ₂ Cu ₃ O ₇								
Cu–O chains	2.04	−1.78, −1.64		Y:2.44	2.66 (2.21)	1.99 (1.87)	1.97 (2.00)	3.03 (2.80)
Cu–O planes	1.52	−1.74, −1.51			2.06 (2.13)	2.01 (2.03)	1.99 (2.03)	

(continued)

Table 9.3 (continued)

Crystal	Atomic charges				Full atomic valences			
	Cu, Pb, Ni	O1	O2	Me	Cu, Pb, Ni	O1	O2	Me
α -PbO	0.91	−0.91			2.38	2.21		
β -PbO	0.88	−0.88			2.41	2.21		
α -PbO ₂	2.78	−1.39			3.95	2.04		
β -PbO ₂	2.80	−1.40			3.95	2.05		
Pb ₂ O ₃	0.94 2.80	−1.11, −1.24			2.32 3.94	2.11 2.07		
		−1.38				2.06		
Pb ₃ O ₄	0.74 3.09	−1.05, −1.24			2.34 3.97	2.10 2.09		

^a Cu, Pb, Ni—atoms with variable valence; oxygen and Me (I,II,III)—atoms with constant valence; crystallographic atomic valences are given in brackets

The numerical values of parameters N , R_0 and B are usually found by fitting the crystallographic valence $\tilde{V}_i$ to the mean value of the stoichiometric atomic valence in the row of the simplest crystals containing the i th atom. One has to be careful in interpreting the bond-valence sums. The drawbacks of the CV definition are evident:

1. Only the central part of the typical valence–bond length curve may be approximated by (9.26) and (9.27).
2. The real interaction between two atoms in a crystal depends not only on the interatomic distance between atoms but also on the covalent or ionic character of the formed chemical bonding (in some cases, this is taken into account by introducing additionally the dependence of the fitting parameters on the oxidation states of bonded atoms).

Nevertheless, the crystallographic valence has a number of practical applications, in particular in the determination of crystal structures or identifying elements that cannot be distinguished by X-ray diffraction. The fitting parameter values for CV given in Table 9.3 were taken from [572].

It can be seen that the CVs of atoms correlate on the whole with their full atomic valence V and oxidation state in the compounds considered. However, the dispersion of CV values is large for an atom with the same oxidation state in different crystals. For example, the CV of the oxygen atom appears to be in the interval 1.5–2.6. The CV approach was used by some authors to find the copper oxidation states in high-temperature superconductors [569]. However, as a rule, these compounds have nonstoichiometric composition, which introduces some uncertainty into their crystal-structure interpretation.

The experimental Cu–O distance in the orthorhombic modification of La₂CuO₄ (see Fig. 2.13) is larger than in the tetragonal one. The corresponding CV of copper is less in the orthorhombic modification. This tendency is reproduced by the calculated full valence values. However, in both La₂CuO₄ modifications, the copper CV values are larger than two (stoichiometric value), while the full valences are closer to this value. The crystal valence of copper atoms also changes when the oxygen vacancies concentrate on the O₁ site (oxygen in chains) in YBa₂Cu₃O₇

(see Fig. 2.15) and change the composition to $\text{YBa}_2\text{Cu}_3\text{O}_6$ and symmetry from orthorhombic to tetragonal. In $\text{YBa}_2\text{Cu}_3\text{O}_7$, both Cu_1 copper atoms in chains and Cu_2 copper atoms in planes have CV values larger than that in CuO crystal (see Table 9.3), and the CV of the Cu_1 atom is somewhat larger. The absence of oxygens on the O_1 site destroys the chain structure of Cu_1 atoms that become linearly coordinated by two oxygen atoms in $\text{YBa}_2\text{Cu}_3\text{O}_6$ and have a CV value close to that of Cu I copper. The five-coordinated Cu_2 atom has a crystal valence close to that of Cu II (see Table 9.3). The calculation of not only the full valences but also other local properties of electronic structure gives more detailed information about the chemical bonding in crystals of metal oxides.

As is seen from Table 9.3, the copper atomic charge Q_{Cu} is close to +1 in the Cu I oxide compounds. This means that the Cu I–O bonding is essentially ionic. The calculated $4s$ population of copper atoms appears to be near zero so that the copper atomic configuration in Cu I oxide crystals is close to $3d^{10}$. The results for Cu II-containing copper oxide compounds indicate that Cu II–O bonding is more covalent compared to Cu I–O bonding; the copper atomic charge in Cu II oxide compounds lies between 1.38 and 1.70 so that the copper atomic configuration appears to be between $3d^{9.6}$ and $3d^{9.3}$. The Cu III atomic charge is close to +2 (see Table 9.3); calculated atomic populations correspond to a $3d^9$ configuration. Thus, there are no Cu^{3+} ions in cuprates, although these compounds do contain Cu III atoms, which lose two electrons to form an ionic bond with oxygen and supply one electron to form the covalent bonds. Calculated atomic charges on alkali and alkali-earth metal atoms (Me) are close to the number of their valence electrons, so that these metal atoms are present as Me^+ and Me^{2+} ions, respectively. As shown in Table 9.3, the calculated charges of the rare-earth atoms Y and La are close to +3.

In Table 9.3, the results suggest that the absolute values of the atomic charge in plumbic oxides PbO_2 are larger than those in plumbous oxides PbO . However, all the lead–oxygen crystals are very far from purely ionic compounds.

The nonequivalent metal atoms in the miscellaneous oxides Cu_4O_3 , Pb_2O_3 , and Pb_3O_4 have different atomic charges, and the charge values are close to those in either higher (CuO , PbO_2) or lower (Cu_2O , PbO) oxides.

We see that the calculated atomic-charge values agree qualitatively with those expected from the chemical point of view. On the other hand, the electronic charge distribution calculated by other approaches (more traditional for solid-state physics) appears to be unrealistic: for example, it was found in an LAPW calculation of the Cu_2O crystal [573] that the atomic charges (estimated by the density integration inside the atomic spheres) are positive for both atoms: $Q_{\text{Cu}} = 2.05$ and $Q_{\text{O}} = 0.40$. LCAO calculations of the electron density and direct integration over a spherical region near atomic cores [574] also do not allow one to distinguish the atomic charges on atoms with different oxidation states (the numerical values for the copper atomic charge in Cu_2O and CuO crystals are practically the same: +0.58 and +0.48, respectively). These examples demonstrate the advantage of quantum-chemical LCAO calculations of the local electronic-structure properties to describe reasonably both the valence and charge states of metal atoms in crystals. This conclusion is important for the study of new complicated crystalline structures, synthesized experimentally. As an example, we refer to the high- T_c

superconductors. It is well known that a small variation of the composition or the way in which the material is prepared may essentially change the superconducting properties. Evidently this is connected with a change of the electronic structure of the superconductor.

In [566] the comparative theoretical analysis of chemical bonding was made in two pairs of copper oxide compounds: (a) orthorhombic and tetragonal modifications of La_2CuO_4 (the latter modification has a structure similar to that of the superconductor $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$) and (b) nonsuperconducting tetragonal $\text{YBa}_2\text{Cu}_3\text{O}_6$ and superconducting orthorhombic $\text{YBa}_2\text{Cu}_3\text{O}_7$ crystals. In accordance with the results of previous band-structure calculation, it was found that La_2CuO_4 and $\text{YBa}_2\text{Cu}_3\text{O}_7$ are metallic with small values of the density of states at the Fermi level, but $\text{YBa}_2\text{Cu}_3\text{O}_6$ is a semiconductor with a forbidden energy gap of 2.5 eV. It was also found that the density of states for the $\text{YBa}_2\text{Cu}_3\text{O}_7$ crystal contains $3d$ Cu I (copper in chains) peak around 13 eV below Fermi level, but in the case of $\text{YBa}_2\text{Cu}_3\text{O}_6$, this peak was absent. An analysis of chemical bonding in high- T_c superconductors and related nonsuperconductor crystals shows changes that take place in the local electronic structure of these substances. As seen in Table 9.3, the charge distribution around the copper atom in the orthorhombic modification of the La_2CuO_4 crystal is practically the same as in the CuO crystal. Contrary to this, in the tetragonal modification of La_2CuO_4 , the copper atomic valence exceeds the ordinary Cu II valence in copper oxide compounds. The calculated atomic charge on the copper atoms in La_2CuO_4 crystals correlates well with that from *ab initio* Hartree–Fock cluster calculation (1.79e) [575]. If we consider the following defect-formation process, the substitution of La III by Sr II atoms, or the addition of oxygen atoms (e.g., $\text{La}_2\text{CuO}_{4.13}$ compound exists), it still further increases the copper valence in La_2CuO_4 . A comparison of the atomic charges and bond orders in $\text{YBa}_2\text{Cu}_3\text{O}_6$ and $\text{YBa}_2\text{Cu}_3\text{O}_7$ crystals shows that electron-density distributions are practically identical in Cu–O planes; see Table 9.3. The main changes in the chemical bonding take place in Cu–O chains. The results in Table 9.3 show that the charge state of Cu I atoms (in Cu–O chains) in $\text{YBa}_2\text{Cu}_3\text{O}_6$ crystal is close to the state of copper atoms in Cu I oxides but that in $\text{YBa}_2\text{Cu}_3\text{O}_7$ they are close to copper atoms in Cu III oxides.

The analysis of calculated bond orders shows that there is no peroxide bonding in copper oxygen superconducting materials. It was also shown by atom–atom potential modeling that even additional oxygen atoms in $\text{La}_2\text{CuO}_{4+x}$ do not cause the formation of peroxide bonds.

One of the questions to be considered is the role of the tetragonal–orthorhombic transition in superconductor materials. To analyze the changes in the electronic structure that are connected with the tetragonal–orthorhombic transition, the $\text{YBa}_2\text{Cu}_3\text{O}_7$ crystal with an oxygen vacancy was considered. The composition of this phase is $\text{YBa}_2\text{Cu}_3\text{O}_6$, but the lattice parameters and space symmetry are the same as those in the $\text{YBa}_2\text{Cu}_3\text{O}_7$ crystal. It was found [555] that differences in atomic charges between perfect $\text{YBa}_2\text{Cu}_3\text{O}_6$ and orthorhombic $\text{YBa}_2\text{Cu}_3\text{O}_6$ do not exceed 0.05. These results show the strong correlation between Cu III (though not Cu^{3+}) atoms' presence and high- T_c superconductivity in copper oxides.

The correlating bonding and structure in Cu II and Ni II mixed oxides is a matter of high interest. The comparative study of the chemical bonding in NiO–CuO and La_2NiO_4 – La_2CuO_4 crystals was made in [566,567]. NiO crystals were calculated in rhombohedral structure, corresponding to nonmetallic antiferromagnetic phase of this crystal. Analysis of local properties of electronic structure of crystals containing a Ni II–O bond with those containing Cu II–O bond allows us to conclude that the former is more ionic than the latter (see Table 9.3). The increase of ionicity degree in the Ni II–O bonding with respect to Cu II–O bonding is understood in terms of the mutual position of the oxygen $2p$ and metal $3d$ subbands that lie nearly in the same energy interval for Cu, whereas the $3d$ Ni subband lies approximatively 2 eV above the center of gravity of the oxygen $2p$ level.

The ionic part of the Ni II–O bonding is the same for NiO and La_2NiO_4 (see Table 9.3). As regards the Cu II–O bonding, the data obtained for La_2CuO_4 as compared to CuO and other Cu II mixed oxides such as Sr_2CuO_3 , Sr_2CuO_2 , and Li_2CuO_2 , atomic charges that are found in the range 1.4–1.6, point to a rather high ionic part of the Cu II–O bonding. Comparing the full atomic valence for Ni II and Cu II (Table 9.3) evidences a striking feature: the quantum-chemical value of the valence fits perfectly the formal oxidation state of Ni, namely, (II), whereas for Cu, the quantum-chemical valence is larger than the oxidation state, with an enhancement for La_2CuO_4 , ($V_{\text{Cu}} = 2.38$). Such a data is likely to depend on an increase of the covalence of the Cu II–O bonding, as compared to the corresponding Ni II–O bonding.

As regards the problem of the true meaning of the (II) valence in tetragonal La_2NiO_4 , quantum-chemical data cannot be considered as contradictory to the occurrence of some Ni II–Ni III oxidation coupled with the presence of interstitial oxygen, which is rather usual for air-prepared polycrystalline La_2NiO_4 .

From the data of Table 9.3, one can get an insight into the anisotropy of the M II–O bonding in La_2MO_4 , *that is*, the electronic anisotropy in the MO_6 octahedra (see Fig. 2.13), in terms of the two following features:

1. The Ni II–O bonding in La_2NiO_4 does not exhibit any significant anisotropic trend: the covalence is rather low and equally distributed in the equatorial plane and the apical direction. Consequently, the nature of the Ni II–O bonding in the NiO_6 octahedra is nearly unchanged when going from the binary oxide NiO to the composite oxide La_2NiO_4 .
2. The increase of the covalent bond order of the Cu II–O bonding, as compared to the Ni II–O one, concerns the Cu II–O in-plane bonds: such Cu–O equatorial bonds are very similar to the Cu II–O bonding in the binary oxide CuO. Conversely, the Cu–O apical bonds are slightly covalent and look like the corresponding Ni–O apical bonds in the NiO_6 octahedra of La_2NiO_4 and NiO, as well. The strong ionic character of the Cu–O apical bonds in La_2CuO_4 results in an unusual overall increase of the atomic charge of Cu (Table 9.3), when compared to CuO and other Cu II mixed oxides. The absence of any significant anisotropic covalent effect of the Ni–O bonding in La_2NiO_4 found in calculations fully agrees with the conclusions of magnetization density studies, which point

to an equal population of $d_{x^2-y^2}$ and d_{z^2} orbitals and no significant covalence in the M–O plane [576]. Moreover, as also stated in [576], the covalent effect to be found in the apical direction of the octahedra is likely to be due not to Ni II but to La III, in terms of a “hybridization between the La 5*d* and O 2*p* bands.” This is consistent with the lowering of the atomic charge of the apical oxygen, as compared to the equatorial one, modeled in La_2NiO_4 (Table 9.3); such a lowering cannot depend on an increase of the covalent effect of the Ni II–O bonding in the apical direction, but more likely it can be ascribed to the covalent character of the La III–O bonding (Table 9.3).

From the main differences in the Ni II–O and Cu II–O bonding emphasized above, it is possible to clear up the problem of the actual nature of the anisotropic effects in the Ni II and Cu II octahedral oxygen coordination in La_2MO_4 oxides (M = Cu, Ni), namely, to appreciate the mutual electronic and geometric or steric contributions. In this respect, Ni II and Cu II behave in a completely different way:

1. The electronic contribution to the overall anisotropy of the NiO_6 octahedra in La_2NiO_4 is nearly absent ($4\text{Ni} - \text{O}_{\text{eq}}$: 1.934 Å, $2\text{Ni} - \text{O}_{\text{ap}}$: 2.243 Å) [577]. This means that the tetragonal distortion of the NiO_6 octahedra largely depends on steric effects originating in the impossibility to match properly the usual La–O and Ni–O bond lengths, 2.57 and 2.06 Å, respectively, when building the structure of La_2NiO_4 , as proposed in [578].
2. The electronic contribution of Cu II in terms of a significant covalent effect of the Cu II–O in-plane bonding results in a cooperative shortening/lengthening of the Cu – O_{eq} and Cu – O_{ap} bonds, respectively: 4 Cu – O_{eq} : 1.904 Å and 2 Cu – O_{ap} : 2.397 Å. The enhancement of the tetragonal distortion of the CuO_6 octahedra results from adding the electronic contribution of Cu II to the typical steric effect of the La_2CuO_4 .

Finally, the quantum-chemical data, as used to compare the anisotropy of the M II–O bonding in the M II octahedral oxygen coordination of La_2MO_4 oxides (M=Ni, Cu), allow the following two features to be emphasized:

- (i) The so-called Jahn–Teller effect of the d^9 Cu II must be understood in terms of an anisotropy of bonding, namely, a strong covalent character of the Cu II–O in-plane bonding that no longer exists in the Cu II–O apical bonding. Such an anisotropic covalent bonding character cannot be found in the high-spin d^8 Ni II; as a consequence, the occurrence of a distortion of the NiO_6 octahedra is related to the steric effects of the geometric structure in question: the rocksalt structure of NiO permits only a very slight distortion of the octahedra, as the structure of La_2NiO_4 results in significant steric constraints on the octahedra.
- (ii) The overall anisotropy of the MO_6 octahedra in the La_2MO_4 oxides (M=Ni, Cu) cannot be fully understood in terms of the typical M II–O bonding properties. The role of La III–O bonding can be held as crucial in enhancing the covalent character of the apical oxygen and consequently increasing the tetragonal distortion of the MO_6 octahedra. This is clear from the data obtained for La_2NiO_4 .

Table 9.4 Crystal structure of titanium oxides: space group, number of formula units per cell Z , and nearest interatomic distances (in Å)

Structure data	TiO(hex)	Ti ₂ O ₃	TiO ₂ (r)	TiO ₂ (a)	TiO ₂ (b)
Group	$P\bar{6}m2$	$R\bar{3}c$	$P4_2/mnm$	$I4_1/amd$	$Pbca$
Z	2	2	2	2	8
$R_{\text{Ti-Ti}}$	3.03	2.58	3.00	3.10	2.95
	3.24	2.99	3.55	3.76	3.06
$R_{\text{Ti-O}}$	2.38	2.02	1.95	1.94	1.86
	3.86	2.07	1.97	1.99	1.92

Thus, anisotropy of the NiO₆ octahedra can be assumed to originate from geometric contributions. Conversely, the anisotropy of the Cu II–O bonding, in terms of a significant covalency of the Cu II–O in-plane bonding, is unambiguously settled. More generally, each increase of the covalency effect of in-plane bonding in MO₆ octahedra results in a corresponding lengthening of the apical M–O bonding. Such an effect, which was previously well evidenced for the anisotropic electronic configurations of some so-called exotic cations such as low-spin Ni³⁺ or low-spin Cu³⁺, is presently being investigated in Ni I–O and Cu I–O bonding of the structures of the reduced phases LaNiO₂ and LaSrNiO₃ [579].

The use of local electronic-structure properties conception in the chemical-bonding analysis was demonstrated also in *ab initio* calculations of crystalline metal oxides, discussed in the next section using the example of titanium oxides.

9.1.3 Chemical Bonding in Titanium Oxides: Periodic and Molecular-Crystalline Approaches

As demonstrated above by the results of semiempirical calculations of metal oxides, the full valence of the metal atom, defined according to (9.13), correlates with the metal oxidation state. Such a conclusion was confirmed later in *ab initio* HF calculations [558] of titanium oxides. Although the quadrivalent state (oxidation state IV) of the titanium atom is the most stable, the existence of oxygen compounds of titanium in formal oxidation states of III and II as well as of a series of nonstoichiometric compounds was established. Table 9.4 presents the space-group symbol, the number of formula units in the cell, and the shortest Ti–Ti and Ti–O experimental distances for TiO in hexagonal structure, Ti₂O₃ in corundum structure, and TiO₂ (in the rutile (r), anatase (a), and brookite (b) modifications).

The titanium oxides are of considerable technological interest, so different theoretical studies of electronic and atomic structure and properties have been performed both for TiO₂ [95,313,580,581] and Ti₂O₃ [582,583] crystals. We are not aware of the existence of the electronic-structure calculations of TiO. The available publications focus attention primarily on description of the band structure and phase stability of titanium oxides and restrict the discussion of the nature of chemical

Table 9.5 Local electronic-structure characteristics of titanium oxides in the restricted Hartree–Fock method

Crystal	Mulliken				Löwdin			
	P_d	Q_{Ti}	V_{Ti}	V_{O}	P_d	Q_{Ti}	V_{Ti}	V_{O}
TiO(hex)	2.38	1.62	2.14	2.04	2.70	1.27	2.30	2.15
Ti ₂ O ₃	1.82	2.26	3.61	2.05	2.50	1.43	3.98	2.30
TiO ₂ (r)	1.46	2.66	3.94	2.08	2.18	1.73	4.18	2.36
TiO ₂ (a)	1.47	2.65	3.98	2.08	2.19	1.72	4.23	2.36
TiO ₂ (b)	1.49	2.63	3.97	2.09	2.21	1.70	4.23	2.38

bonding in these compounds to an analysis of Mulliken atomic charges and overlap populations.

The chemical bonding in titanium oxides was studied in more detail in [558, 559, 561, 584]. The calculations are made by HF LCAO and DFT LCAO methods, incorporated in the computer code CRYSTAL [21]. The core electrons of Ti and O atoms are described by Durand–Barthelat [468] pseudopotentials, and the atomic basis sets were taken from [313], where the outer exponents of the Gaussians were fitted to reproduce the parameters of rutile structure. For the structural parameters those calculated in [313, 582] were taken. The sufficiently good accuracy of the calculations was ensured by the following choice of input computational parameters: 1. the good-quality set of the threshold parameters controlling the accuracy of the bielectronic series in RHF and UHF calculations (10^{-6} , 10^{-6} , 10^{-6} , 10^{-6} , 10^{-12}); 2. the reasonably accurate tolerances controlling the DFT calculations of density, potential, and grid weight (10^{-9} , 10^{-9} , 10^{-14}); 3. the values 10^{-6} and 10^{-5} a.u. for the convergence thresholds of eigenvalues and total energy, respectively; and 4. for the sampling $\mathbf{k}$ -point net of the integration in the reciprocal-space Monkhorst–Pack set with shrinking factors $s_1 = s_2 = s_3 = 6$ was used.

Table 9.5 presents local electronic-structure characteristics of the titanium oxides obtained by the RHF method, namely, the Ti d -orbital populations P_d and atom charges Q_{Ti} , as well as the atomic valences V_A . Also given are the local characteristics calculated in a nonorthogonal atomic basis and a basis orthogonalized according to Löwdin. As follows from a comparison of the results obtained from population analyses by Mulliken and Löwdin, the Löwdin analysis shows the chemical bonding in the crystals under study to be largely covalent, with the total valences of the titanium and oxygen atoms differing substantially from the expected stoichiometric values.

It was shown [13] that the calculations made using a valence atomic basis without polarizing functions in the Löwdin population analysis agree better with the expected values of atomic valences. The population analysis by Mulliken made in a nonorthogonal basis was found to be less sensitive to the inclusion of polarizing functions into the calculation. The results obtained with the restricted and unrestricted HF methods for TiO₂ in formal titanium configuration d^0 do not differ practically from one another. The results of a calculation of the local properties of

Table 9.6 Local properties of chemical bonding in titanium oxide crystals in the restricted and unrestricted HF methods: titanium d -orbital populations P_d , atomic charges Q_A , covalences C_A , atomic valences V_A , and bond orders W_{AB} for nearest-neighbor atoms^a

Local properties	TiO (hex)		Ti ₂ O ₃		TiO ₂ (r)
	RHF	UHF	RHF	UHF	RHF
P_d	2.38	2.34	1.82	1.77	1.46
Q_{Ti}	1.63	1.67	2.26	2.32	2.66
C_{Ti}	0.90	0.69	2.19	1.23	2.15
V_{Ti}	2.14	2.05	3.61	3.01	3.94
Q_{O}	-1.63	-1.67	-1.51	-1.55	-1.33
C_{O}	0.74	0.66	0.94	0.88	1.24
V_{O}	2.04	2.03	2.05	2.05	2.08
$W_{\text{Ti-Ti}}$	0.03	0.01	0.89	0.03	0.01
	0.00	0.00	0.00	0.01	0.01
$W_{\text{Ti-O}}$	0.11	0.10	0.20	0.19	0.36
	0.00	0.00	0.21	0.19	0.30

^a For the TiO₂ crystal, the RHF and UHF results coincide

the three TiO₂ modifications show them to be only weakly sensitive to structural changes.

As seen from Table 9.6, the largest difference between the calculations made in the RHF and UHF approximations was found for Ti₂O₃ in corundum structure (see Fig. 2.19) with a formal titanium atom configuration d^1 , where one can expect substantial spin-polarization and correlation effects. In the Ti₂O₃ case, the RHF method predicts a high bond order between titanium atoms, which, in its turn, results in an overestimated titanium valence. This pattern of chemical bonding is not borne out by experiments. As follows from Table 9.6, an increase in the degree of Ti oxidation from II to IV gives rise to an increase in the charge on the titanium atom, but the relative ionicity and the absolute value of the charge on the oxygen atom decrease. UHF calculations show that, in all the above insulator oxygen compounds of titanium, there is no strong covalent interaction among the Ti atoms.

An appreciable role in transition-metal compounds is played by electron correlation effects, which may be taken into account in periodic DFT calculations or within the framework of multiconfigurational methods employing the cluster model of the crystal. In particular, of interest is the question to what extent the single-determinant UHF method (applied in the periodic LCAO calculations of solids) may account for the correlation effects. In the general case, only a qualitative answer to this question is possible. The comparison of the whole set of local properties for rutile TiO₂ and corundum Ti₂O₃ structures as seen from results of calculations [559, 561, 584] demonstrates the different role of correlation effects on the chemical bonding in these two solids. In Tables 9.7 and 9.8, results are given for RHF, UHF, KS (Kohn–Sham Hamiltonian with BLYP exchange–correlation functional—nonspin-polarized), and KSS (the same KS Hamiltonian with inclusion of spin polarization).

Table 9.7 DFT and HF results for rutile TiO_2 crystal (Mulliken population analysis)

Method	E (a.u.)	Q_A	C_A	V_A	$W_{\text{Ti-O1}}$	$W_{\text{Ti-O2}}$
RHF	-69.776	2.66 -1.33	2.15 1.24	3.94 2.08	0.36	0.30
UHF						
$S_Z = 0$	-69.776	2.66 -1.33	2.15 1.24	3.94 2.08	0.36	0.30
$S_Z = 1$	-69.491	2.80 -1.40	1.99 1.11	3.97 2.07	0.32	0.26
KS (BLYP)	-71.348	1.88 -0.94	3.18 1.85	4.06 2.25	0.50	0.43
KSS (BLYP)						
$S_Z = 0$	-71.351	1.88 -0.94	3.18 1.85	4.06 2.24	0.50	0.43
$S_Z = 1$	-71.481	2.24 -1.12	2.73 1.60	3.99 2.17	0.43	0.39
HB (LYP)	-70.834	2.64 -1.32	2.17 1.25	3.94 2.09	0.36	0.30
HBS (LYP)						
$S_Z = 0$	-70.834	2.64 -1.32	2.17 1.25	3.94 2.09	0.36	0.30
$S_Z = 1$	-70.554	2.80 -1.40	1.99 1.11	3.97 2.07	0.32	0.27

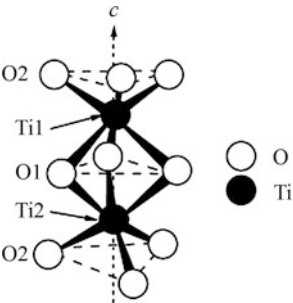
Also given are results for hybrid spinless and spin-dependent schemes using HF exchange and LYP correlation in the Hamiltonian (HB and HBS, respectively).

As follows from the results of the calculations, the effects of electronic correlation on local properties of the electronic structure of two crystals under consideration have both similarities and differences. Their explanation can be given if the peculiarities of the structure are taken into account. In both crystals the essentially covalent Ti–O interaction takes place as the two spheres of the Ti atom's nearest neighbors are formed by oxygen atoms: 1. in TiO_2 , the Ti atom is surrounded by four oxygens at 1.95 Å and the next two oxygens at 1.97 Å *that is*, oxygens form a distorted octahedron (see Fig. 2.11). 2. In Ti_2O_3 , crystal six oxygens are grouped into two triangles (with close Ti–O distance 2.02 and 2.07 Å, respectively) (see Fig. 9.1). The Ti–Ti atoms' configuration in two crystals is different: 1. in TiO_2 crystal, there are two Ti atoms at distance 2.99 Å as a third neighbor of the Ti atom. In Ti_2O_3 crystal, each Ti atom interacts with only one Ti atom at the distance 2.58 Å, being smaller than that in TiO_2 crystal. The results, given in Tables 9.7 and 9.8, may be explained when only the three first neighbors of the Ti atom are considered (from the analysis of calculated bond orders, it follows that the interactions with more distant atoms are sufficiently weak). From Tables 9.7 and 9.8, it is seen that both HF and KS calculations demonstrate the essential role of covalence in both crystals due to Ti–O interactions. When comparing atomic charges Q_{Ti} for the same calculational scheme, one finds that the Ti–O bonding in TiO_2 crystal is partly more ionic.

Table 9.8 DFT and HF results for Ti_2O_3 crystal in corundum structure (Mulliken population analysis)

Method	E (a.u.)	Q_A	C_A	V_A	$W_{\text{Ti-Ti}}$	$W_{\text{Ti-O1}}$	$W_{\text{Ti-O2}}$
RHF	-108.029	2.26 -1.51	2.20 0.94	3.61 2.05	0.87	0.20	0.21
UHF							
$S_Z = 0$	-108.362	2.32 -1.54	1.23 0.88	3.01 2.05	0.03	0.19	0.19
$S_Z = 1$	-107.902	2.24 -1.49	2.37 0.96	3.72 2.05	0.49	0.20	0.20
KS (BLYP)	-110.682	1.65 -1.10	3.47 1.63	4.13 2.18	0.34	0.35	0.30
KSS (BLYP)							
$S_Z = 0$	-110.702	1.69 -1.13	3.11 1.60	3.85 2.18	0.10	0.33	0.30
$S_Z = 1$	-110.744	1.68 -1.12	3.04 1.56	3.79 2.15	0.19	0.33	0.28
HB (LYP)	-109.672	2.24 -1.50	2.22 0.96	3.61 2.05	0.86	0.20	0.21
HBS (LYP)							
$S_Z = 0$	-110.027	2.31 -1.54	1.25 0.90	3.01 2.05	0.03	0.19	0.20
$S_Z = 1$	-109.588	2.24 -1.49	2.41 0.97	3.74 2.05	0.51	0.20	0.20

Fig. 9.1 Geometric structure of $[\text{Ti}_2\text{O}_9]^{12-}$ cluster, modeling Ti_2O_3 crystal in corundum structure



For TiO_2 crystal the Ti–Ti interaction is weak (the corresponding bond orders $W_{\text{Ti-Ti}}$ are in the range of values 0.01–0.02 for all calculation schemes and are not given in Table 9.7). For Ti_2O_3 crystal the results of calculations depend on the spin correlation: 1. in the RHF method, bond order $W_{\text{Ti-Ti}}$ appears to be large (0.87) and does not practically change in hybrid HF–KS calculations (HB) without spin; 2. for spin projection $S_z = 0$ (antiferromagnetic case), $W_{\text{Ti-Ti}}$ is close to zero in UHF, KSS, and HBS calculations, which means that spin-correlation effects are mainly important when the Ti–Ti interaction is considered; and 3. for spin projection $S_z = 1$ (ferromagnetic case), not only spin correlation but also the Coulomb one influences

$W_{\text{Ti-Ti}}$: UHF value $W_{\text{Ti-Ti}} = 0.49$ decreases to $W_{\text{Ti-Ti}} = 0.19$ in KSS calculation. It is seen also that in UHF and Becke exchange Hamiltonians spin correlation is described in a different manner: the $W_{\text{Ti-Ti}}$ value decreases from 0.49 (UHF) to 0.19 (KSS). Analyzing the total energy E per unit cell, one can draw interesting conclusions from Tables 9.7 and 9.8.

In TiO_2 crystal: 1. spin-correlation effects are small for $S_z = 0$ (antiferromagnetic ordering practically does not change E , as seen from a comparison of the RHF–UHF, KS–KSS, and HB–HBS results). 2. The energy of the ferromagnetic state ($S_z = 1$) is higher than for the antiferromagnetic state ($S_z = 0$) for UHF and HBS calculations. It again shows the difference between HF and Becke approximations for exchange. This difference is due to the nonlocal exchange in the HF Hamiltonian (the one-electron-density matrix offdiagonal elements are not taken into account in DFT approximation for exchange).

In Ti_2O_3 crystal, the same difference in the total energy for $S_z = 0$ and $S_z = 1$ cases was found: in HF and HBS calculations, antiferromagnetic ordering gives an energy gain compared with the diamagnetic picture (compare in Table 9.8 the total energy for $S_z = 0$ and $S_z = 1$ in UHF and HBS calculations); however, Becke exchange gives the opposite order of the total energies (compare $S_z = 0$ and $S_z = 1$ for KSS calculations). As for covalences of oxygen atoms and $W_{\text{Ti-O}}$, one can draw from Tables 9.7 and 9.8 the following conclusions: (1) only spin correlation of Ti atoms gives small changes for these properties of electronic structure in both crystals (compare in Tables 9.7 and 9.8 RHF–UHF, KS–KSS, and HB–HBS results). (2) Inclusion of Coulomb correlation with Becke exchange gives a more covalent picture of chemical bonding (compare the results for RHF and KS calculations), but only the correlation correction gives small changes of the covalence of chemical bonding (compare the results for RHF and HB calculations).

As was demonstrated in [555], the full valence of the metal atom, calculated for different metal oxides according to definition (9.13), correlates with the oxidation state in the semiempirical calculations, implicitly taking into account the correlation effects (see Chap. 6). In TiO_2 and Ti_2O_3 crystals, the Ti atom oxidation state should be +4 and +3, respectively. The calculated total valence V_{Ti} is close to oxidation state 4 for all calculations of TiO_2 (see Table 9.7) but strongly depends on the spin-correlation description for Ti_2O_3 (see Table 9.8). The calculated total valence V_{O} appears to be close to a reasonable value, 2.0, in all cases.

For rutile TiO_2 the LCAO results for Mulliken charges and the Ti–O overlap population can be compared with those found in DFT PW calculations [585] after projecting the eigenstates onto a localized basis set of atomic pseudo-orbitals. In KS LCAO calculations, $Q_{\text{Ti}} = 1.88$ and overlap populations of Ti–O bonds are 0.11 and 0.10 for nearest and next-nearest oxygens, respectively. In PW calculations [20], $Q_{\text{Ti}} = 1.46$, and the overlap populations are 0.35 and 0.43, respectively. This comparison shows that the calculated local properties' numerical values depend on the choice of basis set used in calculations (LCAO or PW sets). Moreover, in PW calculations the procedure of projection is used to receive atomic orbitals (see Sect. 9.1.6), which is not necessary in LCAO calculations.

From the discussion of the results obtained, it follows that the spin-correlation effects are described in an essentially different manner in HF and DFT calculations for Ti_2O_3 crystal and as a result give different descriptions of Ti–Ti interaction: in the HF method, this interaction is weak (for energetically more favorable antiferromagnetic ordering); in the DFT method, the ferromagnetic ordering appears to be more favorable, and Ti–Ti interaction remains essential.

It seems reasonable to use post-HF descriptions of spin-correlation effects other than that used in HF and DFT methods. For this, one can perform, say, UHF and CASSCF electronic-structure calculations of reasonably selected clusters of the crystal under consideration to get single-determinant UHF and multiconfigurational CASSCF wavefunctions. Then, expanding UHF β -MOs over an α set and inserting these expansions in the UHF determinant, we obtain a certain multiconfigurational wavefunction that is, in general, a mixture of different spin states. Annihilation of the highest-spin contaminants leads to the multiconfigurational wavefunction that should be compared with the CASSCF one. If these functions are similar, that is, in both functions the same determinants are dominating, then one can state that the UHF method accounts for part of the Coulomb correlation effects. Estimation of relevant energies may give an impression of what part of the correlation energy (in comparison with the CASSCF method) is obtained on the UHF level. Then, all qualitative conclusions concerning a cluster may be directly applied to the corresponding crystal. In particular, if local molecular characteristics (such as atomic charges, bond orders, valences, and covalences) of a cluster are notably affected by correlation effects and UHF cluster calculation reproduces this tendency, then the UHF calculation of a crystal should certainly display the same tendency.

There exists one simple but important case where more detailed analysis is possible. Indeed, let us consider a molecular system (cluster) with a nondegenerate singlet ground state that can be described by a MCSCF wavefunction with dominating contribution of only two configurations:

$$\Psi_{\text{MCSCF}} = C_1 \det |\dots \varphi_h \alpha \varphi_h \beta| + C_2 \det |\dots \varphi_l \alpha \varphi_l \beta| \quad (9.28)$$

With the aid of a nondegenerate (nonorthogonal) transformation (for the standard case $C_1 > 0$ and $C_2 < 0$), generalized valence-bond orbitals may be constructed:

$$\varphi_a = \sqrt{\frac{1}{2}} \left\{ \sqrt{C_1} \varphi_h + \sqrt{|C_2|} \varphi_l \right\} \quad (9.29)$$

$$\varphi_b = \sqrt{\frac{1}{2}} \left\{ \sqrt{C_1} \varphi_h - \sqrt{|C_2|} \varphi_l \right\} \quad (9.30)$$

Simple algebraic manipulations lead to the conclusion that

$$\Psi_{\text{MCSCF}} \simeq \Phi_{ab} + \Phi_{ba} \quad (9.31)$$

where

$$\Phi_{ab} = \det |\dots \varphi_a \alpha \varphi_b \beta| \quad (9.32)$$

and

$$\Phi_{ba} = \det |\dots \varphi_b \alpha \varphi_a \beta| \quad (9.33)$$

are typical single-determinant UHF configurations. These determinants correspond to zero projection of the total spin but are not, in general, S^2 eigenfunctions. Their symmetrical combination gives the initial singlet wavefunction (9.28), whereas the antisymmetrical combination gives the related triplet state. In general, the nondiagonal matrix element $\langle \Phi_{ab} | \hat{H} | \Phi_{ab} \rangle$ differs from zero, and its absolute value may serve as a certain measure of the UHF method's capability to account for Coulomb correlation effects. Indeed, if this matrix element is small (in absolute value), then singlet and triplet states are energetically close and the UHF method for a singlet state accounts for about the same part of the correlation effects as the MCSCF one with wavefunction (9.28).

Calculations of the lowest singlet and triplet states of cluster $[\text{Ti}_2\text{O}_9^{12-}]$ (see Fig. 9.1) were performed by UHF and CASSCF methods using the GAMESS program set for molecular calculations [33]. The cluster includes two nearest Ti atoms and their nearest oxygen neighbors. The initial MOs for this cluster were obtained by the RHF method with C_{3h} as the point-symmetry group. The active space of the CASSCF method involved five highest occupied and three lowest virtual MOs (active space $[2a'2a''2e']^{10}$). From Table 9.9 it is seen that the cluster chosen reasonably reproduces the Ti atom's local properties compared with periodic calculations for $S_z = 0$ (see Table 9.8). In UHF calculations, $Q_{\text{Ti}} = 2.22$ (cluster model), $Q_{\text{Ti}} = 2.32$ (periodic model), $C_{\text{Ti}} = 1.37$ (cluster model), and $C_{\text{Ti}} = 1.23$ (periodic model). It turned out that the singlet state of the cluster under consideration is described by two configurational wavefunctions:

$$0.8[\varphi_h^2 \varphi_l^0] - 0.6[\varphi_h^0 \varphi_l^2] \quad (9.34)$$

whereas the related triplet state with $S_z = 1$ is reasonably described by a single determinant.

The comparison of the total energies for the cluster shows (see Table 9.9) that the UHF calculation reproduces well the small difference of the CASSCF energies for the total spin values $S = 0$ and $S = 1$. Moreover, as seen from Table 9.9, the UHF calculation describes correctly the influence of the correlation effects on the Ti–Ti bond-order value. Indeed, in RHF calculations this bond order constitutes 0.88, whereas in UHF calculations the bond-order values are 0.03 for $S_z = 0$ and 0.01 for $S_z = 1$, in full accordance with CASSCF calculations (0.09 for $S = 0$ and 0.01 for $S = 1$). At the same time, the Ti atomic charges are practically not affected by the method used.

Calculations of the electronic structure of crystals TiO_2 and Ti_2O_3 and corresponding cluster show that numerical results for local properties of the electronic

Table 9.9 Energies and local characteristics of electronic structure of molecular cluster $[\text{Ti}_2\text{O}_9]^{12-}$ in UHF and MCSCF calculations

Characteristics of electronic structure	UHF		MCSCF	
	$S_z = 0$	$S_z = 1$	$S_z = 0$	$S_z = 1$
E (a.u.)	-137.874	-137.867	-137.913	-137.904
Q_{Ti}	2.22	2.28	2.11	2.12
Q_{O1}	-1.68	-1.68	-1.63	-1.64
Q_{O2}	-1.90	-1.90	-1.89	-1.89
$W_{\text{Ti-Ti}}$	0.03	0.01	0.09	0.01
$W_{\text{Ti-O1}}$	0.17	0.17	0.19	0.20
$W_{\text{Ti-O2}}$	0.27	0.27	0.31	0.32
C_{Ti}	1.37	1.34	1.62	1.56
C_{O1}	0.63	0.62	0.70	0.71
C_{O2}	0.21	0.21	0.23	0.24
V_{Ti}	3.01	3.02	3.07	3.04
V_{O1}	2.02	2.02	2.02	2.03
V_{O2}	2.01	2.01	2.01	2.01

structure of crystals (atomic charges, covalences, free and total valences, and bond orders) depend on (a) choice of basis for calculation (LCAO, PW), (b) choice of Hamiltonian (RHF, UHF, DFT), and (c) choice of population analysis (POPAN) scheme (Löwdin, Mulliken). The effects of electron correlation on local properties may be estimated using (a) periodic and cluster DFT and hybrid HF–DFT calculations in the periodic model, (b) post-HF calculations in the molecular cluster model, and (c) the results of (a) and (b) agree when the appropriate cluster choice is made and the same basis and population analysis are used.

To minimize the essential dependence of results on the basis-set choice and POPAN, it is reasonable to generate Wannier-type atomic functions that are orthogonal and localized on atomic sites. These functions can be generated from Bloch-type functions (after relevant symmetry analysis); see Chap. 3. In the next section it is shown that the results of POPAN with use of Wannier-type atomic functions weakly depend on the basis choice in Bloch-function LCAO calculations.

9.1.4 Wannier-Type Atomic Functions and Chemical Bonding in Crystals

As we have seen above chemical bonding in crystals (as well as in molecules) is analyzed in terms of the local properties of the electronic structure, obtained from the one-electron-density matrix, written in a localized basis. Since local properties of electronic structure are essential ingredients of a number of theories and models (e.g., the numerical values of atomic charges are used in the atom–atom potentials of the shell model), their estimation is of great importance. Traditionally, the same AO basis is used both in LCAO SCF calculations and in the local properties definition,

as was noted above. However, this approach is not always reliable, since the results of the population analyses are often strongly dependent on an inclusion of diffuse orbitals into the basis (useful for the electronic-structure calculations) and on the scheme chosen for the population analysis.

As discussed in Chap. 3, the variational method of localized functions generation allows development of an approach of the chemical-bonding analysis, which is much less basis-set dependent than the conventional approaches. The population analysis in this case is done using the density matrix given in the minimal valence basis of Wannier-type atomic orbitals (WTAOs)—Wannier functions centered on atoms and having the behavior of atomic-valence states in the cores of atoms [45, 587, 588]. WTAOs are analogous to atomic functions in form and by symmetry, but, in contrast to the initial LCAO basis, they are directly connected with the calculated electronic band structure and the Bloch states involved. WTAOs are constructed from the occupied and some vacant Bloch states chosen so that they assure the maximal localization for the corresponding WTAOs (see Chap. 3). The summary of the results of WTAO application for the calculations of local properties of the electronic structure of periodic systems is given in [589].

WTAOs are defined as the Wannier functions that are constructed from a set of specially chosen occupied and vacant bands and have a definite symmetry (they are centered on atoms and transform via irreducible representations (irreps) of the corresponding site groups). Thus, the index t in (3.114) may be substituted by several indices— i, j, a, β, μ —that reflect the symmetry properties of the WTAOs— $W_{ija}^{\beta\mu}(\mathbf{r} - \mathbf{a}_n)$: the index a marks the symmetrically nonequivalent atoms, and the index j runs through the set of symmetrically equivalent atoms of the type a ; the Wyckoff positions of these atoms $\mathbf{q}_a$ are characterized by their site groups, whose irreps are labeled by the index β , the index i numbers the basis functions of the irrep β , and the index μ discriminates between the independent sets of the functions transforming according to the same irrep β . The requirement for WTAOs to have fixed symmetry properties implies additional restrictions on the matrices $U(\mathbf{k})$ in (3.112). These restrictions can be completely taken into account by using, instead of canonical Bloch orbitals, their linear combinations, symmetrized according to the desired irreps of the site-symmetry groups of atoms [45].

WTAOs were generated by the variational method [588], which allows both orthogonal $W_{ija}^{\beta\mu}(\mathbf{r} - \mathbf{a}_n)$ and nonorthogonal $V_{ija}^{\beta\mu}(\mathbf{r} - \mathbf{a}_n)$ sets of symmetry adapted WTAOs to be obtained. In this method the functional

$$I_{\beta\alpha} = \int \omega_{\beta\alpha} \left| V_{11a}^{(\beta,1)}(\mathbf{r}) \right|^2 d\mathbf{r} \quad (9.35)$$

with the weight function

$$\omega_{\beta\alpha} = \left(\pi r_{\beta\alpha}^2 \right)^{-3/2} \exp \left(- \frac{(\mathbf{r} - \mathbf{q}_a)^2}{2r_{\beta\alpha}^2} \right) \quad (9.36)$$

is maximized ($r_{\beta\alpha}^2$ is a parameter, for which a value of $1 \text{ \AA}$ was used). The orthogonal WTAOs $W_{ija}^{\beta\mu}(\mathbf{r} - \mathbf{a}_n)$ are obtained from the nonorthogonal ones $V_{ija}^{\beta\mu}(\mathbf{r} - \mathbf{a}_n)$ via Löwdin's procedure:

$$\mathbf{W} = \mathbf{V} (S^{(V)})^{-1/2} \quad (9.37)$$

where $S^{(V)}$ is the overlap matrix of nonorthogonal WFs $V_{ija}^{\beta\mu}(\mathbf{r} - \mathbf{a}_n)$, and $\mathbf{W}$ and $\mathbf{V}$ are row vectors constituted by the sets of the orthogonal and nonorthogonal WFs, correspondingly. The orthogonalization procedure can be performed either in the direct or reciprocal space. The latter is computationally faster.

Before constructing the minimal basis of WTAOs, one should choose the energy bands whose states are to be used in the process of the WTAOs generation. For each of the WTAOs, a band or a group of bands is chosen according to the following criteria: the band states should be compatible with the corresponding WTAOs by symmetry, in the context of the induced representations (indreps) theory (see Chap. 3) and provide the maximal localization for them. Hereafter, we mark such bands by the type of the WTAOs corresponding to them (e.g., s -band of the oxygen atom: the s -WTAOs centered on oxygen and constructed from the states of this band appear to be the most localized comparing to those constructed from any other states). After the desired bands for all the WTAOs are chosen, the final WTAOs are constructed using the states from this group of bands. When the WTAOs (orthogonal or nonorthogonal) are found, the density matrix is calculated in the localized basis of these functions. The local properties are expressed via the matrix elements of this matrix.

WTAOs' analog of Mulliken population analysis is made using nonorthogonal WTAOs.

Let us now consider WTAOs $V_{vA}(\mathbf{r} - \mathbf{a}_n)$ (v -th WTAO of atom A in the n th cell) as the linear combinations of Bloch functions:

$$V_{vA}(\mathbf{r} - \mathbf{a}_n) = \sum_{\tau k} b_{\tau k, vA n} \varphi_{\tau k}(\mathbf{r}), \quad \text{or} \quad \mathbf{V} = \varphi b, \varphi = \mathbf{V} b^{-1} \quad (9.38)$$

where Bloch functions $\varphi_{\tau k}(\mathbf{r})$ are given in LCAO or PW basis. The density matrix in the corresponding basis $\rho^{(V)}$ can be written in the following way:

$$\rho^{(V)} = 2\bar{b}^{-1}\bar{b} \quad (9.39)$$

where $\bar{b}$ is the truncated matrix b with rows corresponding only to the occupied states.

For the orthogonalized WTAOs

$$W_{vA}(\mathbf{r} - \mathbf{a}_n) = \sum_{\tau k} d_{\tau k, vA n} \varphi_{\tau k}(\mathbf{r}), \quad \text{or} \quad \mathbf{W} = \varphi d, \varphi = \mathbf{V} d f^\dagger \quad (9.40)$$

the density matrix $\rho^{(V)}$ is given by

$$\rho^{(V)} = 2\bar{d}^\dagger \bar{d} \quad (9.41)$$

The electronic population N_{An} of an atom A in the n th primitive cell and an order of the bond $W_{A0,Bn}$ between an atom A of the reference cell and an atom A' in the n th cell can be obtained from the density matrix (9.41):

$$N_{An} = N_{A0} = \sum_v \rho_{vv}^{A0,A0} \quad (9.42)$$

$$W_{A0,Bn} = \sum_{\mu\nu} \rho_{\mu\nu}^{A0,Bn} \rho_{\nu\mu}^{Bn,A0} \quad (9.43)$$

Using these quantities one can obtain the atomic charge Q_A (9.10) of an atom A , the covalence C_A (9.12), and total valence V_A (9.13) of this atom.

To demonstrate the efficiency of WTAO use for chemical-bonding analysis, we consider at first the cubic crystals with the perovskite structure [587]. The LCAO approximation in the HF and DFT methods was used to calculate the band structure and the Bloch functions of bulk SrTiO_3 (STO), BaTiO_3 (BTO), PbTiO_3 (PTO), and LaMnO_3 (LMO) crystals. The Hay–Wadt pseudopotentials [467] were adopted: small core for Ti, Sr, Ba, La, and Mn atoms and large core for Pb atoms. The oxygen atoms were included with the all-electron basis set. The optimized Gaussian-type atomic basis was taken from [590], where the same pseudopotentials were used. The basis optimization made it possible to obtain the lattice constant, bulk modulus, and elastic constants of the considered crystals that were in good agreement with the experimental data. For the exchange-correlation functional, the hybrid HF–DFT form (B3PW) was used, as it reproduces, for optimized basis sets, optical bandgaps close to the experimental values [590].

The Monkhorst–Pack [14] mesh of $4 \times 4 \times 4 = 64$ k -points, used in the calculations, corresponds to a cyclic model with 64 primitive unit cells in the direct lattice (see Chap. 3). An increase of this number in the band-structure calculations up to $8 \times 8 \times 8 = 512$ does not lead to any significant changes in the values of the one-electron energies.

The cubic structure of perovskite-like ABO_3 compounds is characterized by the primitive cubic lattice with the O_h^1 ($Pm\bar{3}m$) space group (see Sect. 2.3.2). The A-atoms and B-atoms occupy the Wyckoff positions a (0,0,0) and b (0.5,0.5,0.5), correspondingly, with the site group O_h . The oxygen atoms occupy c (0.5,0.5,0) positions, site group D_{4h} . The minimal atomic-like basis for the crystals under consideration consists of s - and p -type functions of the oxygen atoms, s - and d -type functions of the Ti atoms, and s - and p -type functions of Sr, Ba, and Pb in STO, BTO, PTO, or s - and d -type functions of La and Mn in LMO. So these are the types of WTAOs to be used in the population analysis for the compounds under consideration. Table 9.10 lists the symmetries of these functions.

Table 9.10 The symmetry properties of the WTAOs of the minimal valence basis for STO, BTO, PTO, and LMO crystals

Atom	Function's type	Symmetry
Sr, Ba, Pb	s	(a, a_{1g})
	p	(a, t_{1u})
La	s	(a, a_{1g})
	d	$(a, t_{2g}) + (a, e_g)$
Ti, Mn	s	(b, a_{1g})
	d	$(b, t_{2g}) + (b, e_g)$
O	s	(c, a_{1g})
	p	$(c, a_{2u}) + (c, e_u)$

Once the types of WTAOs are determined, one should find the energy-band states corresponding to these WTAOs. First, the bands to be chosen should be symmetrically compatible with the corresponding WTAOs (see [588] for details). Second, the WTAOs constructed from the Bloch states of the chosen bands should be principally the most localized WTAOs of the corresponding type. The analysis of the electronic structure of STO and BTO has shown (excluding the semicore states from consideration) that the oxygen s - and p -bands and the Sr (Ba) atom p -bands form 15 upper valence-band states (see also next section). The Ti atom d -states form the five lowest conduction bands, while the Sr (Ba) and the Ti atom s -states are located among vacant conduction-band states very high in energy. In the case of PTO, the difference in the location of the bands is that the Pb atom s -band is one of the valence bands and the Pb atom p -bands are vacant and lie high in the conduction band. This agrees with the results of DFT LDA calculations [591].

Unlike STO, BTO, and PTO, the electronic structure of cubic LMO is metallic both in HF and DFT calculations (a nonzero bandgap in LMO appears only if an orthorhombic structure with four formula units in the primitive cell is considered). The s - and p -bands of the oxygen atoms are occupied. As in STO and BTO, the s -bands of the metal atoms are located at high energies. But the d -bands of both metal atoms are located in the region of the Fermi energy. These bands are partly occupied and partly vacant, which is caused by the metallic nature of the calculated electronic structure.

The WTAOs that are used in the population analysis are built from the space of all the chosen bands taken together. The density matrix is then calculated using the coefficients connecting the orthogonal or nonorthogonal WTAOs and the occupied Bloch states.

In Table 9.11, the atomic charges for STO, BTO, and PTO, correspondingly, calculated by the WTAOs technique and using the traditional Mulliken population-analysis scheme are compared.

The Mulliken atomic charges coincide with those given in [590]. The results of the WTAO population analysis in these three crystals show the following: (1) the results of population analysis performed on orthogonal and nonorthogonal WTAOs are close. (2) The fully ionic charge +2 for the Sr, Ba, or Pb atoms remains practically the same for both methods of the electronic-structure calculation—Hartree–Fock and DFT. The only exception is the orthogonal WTAOs analysis in

Table 9.11 Atomic charges in cubic ATiO_3 ($A=\text{Sr}, \text{Ba}, \text{Pb}$)

Method of electronic- structure calculation	Population-analysis scheme	Atomic charges, $ e $		
		Sr	Ti	O
HF	Nonorthogonal WTAO	2.00	3.20	-1.73
	Orthogonal WTAO	2.00	3.13	-1.71
	Mulliken	1.92	2.76	-1.56
DFT	Nonorthogonal WTAO	2.00	2.68	-1.56
	Orthogonal WTAO	2.00	2.63	-1.54
	Mulliken	1.87	2.35	-1.40
HF		Ba	Ti	O
	Nonorthogonal WTAO	2.00	3.19	-1.73
	Orthogonal WTAO	2.00	3.16	-1.72
DFT	Mulliken	1.86	2.82	-1.56
	Nonorthogonal WTAO	2.00	2.65	-1.55
	Orthogonal WTAO	2.01	2.60	-1.54
HF	Mulliken	1.80	2.37	-1.39
		Pb	Ti	O
	Nonorthogonal WTAO	1.99	3.27	-1.75
DFT	Orthogonal WTAO	1.89	3.14	-1.68
	Mulliken	1.59	2.79	-1.46
	Nonorthogonal WTAO	1.99	2.72	-1.57
DFT	Orthogonal WTAO	1.93	2.64	-1.52
	Mulliken	1.34	2.34	-1.23

PTO, but even in this case the charge is very close to +2. The reason for such a high ionicity is related to the high-energy location of the s -bands of the Sr and Ba atoms and the p -bands of Pb atom, which leads to a negligible contribution of the corresponding WTAOs to the covalence of these atoms. The switch from the HF calculations to DFT practically does not affect the location of high-lying vacant bands of the Sr, Ba, and Pb atoms, and, therefore, no covalence for these atoms appears. On the contrary, the traditional Mulliken analysis displays some covalence for these atoms, which increases in the case of DFT calculations. This is especially noticeable in a PTO crystal. (3) The Ti and O atom charges differ from the purely ionic ones (indicating a partial covalence of the Ti and O atoms). For these atoms the covalence is higher in the DFT calculations than in the HF ones. This correlates with the decrease of the bandgaps in DFT calculations compared to the HF ones (in DFT calculations the d -bands of the Ti atom shift down and become closer to the valence oxygen bands). As a result, mixing of the vacant states of the Ti atom d -bands with the oxygen WTAOs increases, generating the larger values of the covalence for these atoms. (4) The results of the WTAO analysis demonstrate a mixed (ionic-covalent) character of chemical bonding in ABO_3 crystals. However, the ionicity, calculated by the WTAOs method, appears to be larger than that obtained in the traditional Mulliken population analysis. (5) The values of atomic charges in all the three considered perovskite-type crystals are close.

Table 9.12 Atomic charges in cubic ATiO_3 ($\text{A}=\text{Sr}, \text{Ba}, \text{Pb}$)

Method of electronic- structure calculation	Order of Ti– O bond	Covalence			Full valence		
		Sr	Ti	O	Sr	Ti	O
HF	0.24	0.00	1.47	0.51	2.00	4.01	2.01
DFT	0.36	0.00	2.28	0.82	2.00	4.06	2.02
		Ba	Ti	O	Ba	Ti	O
HF	0.24	0.00	1.46	0.51	2.00	4.01	2.01
DFT	0.37	0.01	2.33	0.83	2.01	4.06	2.02
		Pb	Ti	O	Pb	Ti	O
HF	0.22	0.02	1.35	0.47	2.00	4.01	2.01
DFT	0.35	0.04	2.23	0.80	2.02	4.06	2.02

Table 9.13 Local properties of electronic structure of cubic LaMnO_3

Atomic charges			Bond orders		Covalence			Full valence		
La	Mn	O	La–O	Mn–O	La	Mn	O	La	Mn	O
2.48	2.09	–1.53	0.08	0.16	1.00	2.48	0.80	3.04	3.68	1.98

The values of some other local characteristics of the electronic structure of STO, BTO, and PTO—bond orders, covalences, and full valences of atoms—are listed in Table 9.12. These values correspond to nonorthogonal WTAOs analysis. The results given in Table 9.12 allow the following to be concluded: (1) the numerical values of the local characteristics of the electronic structure of the cubic STO, BTO, and PTO are very close. (2) The covalence in these crystals appears only in the nearest-neighbor Ti–O bonds (all the other bonds manifest almost no covalence both in HF and DFT calculations). Each Ti atom has six bonds of this type, and each oxygen atom two bonds. In DFT calculations the value of the bond order is larger than in HF ones. (3) Both in the DFT and HF calculations, the values of the total calculated valence of the metal atoms practically coincide with the values of the oxidation state used by chemists for these compounds.

The population analysis is not entirely correct for metallic crystals, because they are characterized by a special metallic type of bonding. But since the nonconducting state in LMO arises already within small distortions from the cubic structure, a formal population analysis performed on the cubic structure can show some tendencies in the local properties. Their values for the cubic LMO obtained with the help of the orthogonal WTAOs in HF calculations are given in Table 9.13.

Analyzing these values one can conclude the following: (1) some of the results are principally different from those of STO, BTO, and PTO. These are a nonzero covalence of the A (La) atom, a nonzero La–O bond order, the calculated valence of the B (Mn) atom is different from the expected one. Probable reasons for these results are connected with the metallic nature of the considered crystal in cubic structure and with the difference of the LMO crystal from STO, BTO, or PTO. (2) On the other hand, the value of the La atomic charge is relatively close to the

fully ionic one +3. Besides, the calculated valences of the La and oxygen atoms are similar to those obtained in STO, BTO, and PTO crystals. This indicates the similarity between these crystals and LMO, manifested in spite of the metallic nature of the latter. (3) The largest value of a bond order in LMO corresponds to the nearest-neighbor Mn–O bond. This correlates with the interatomic charge distribution in STO, BTO, and PTO. The difference is in the value of the bond order—in LMO this bond order is smaller, while the covalence (which is, actually, the sum of all the bond orders) of the Mn atoms practically coincides with that of the Ti atoms in the other three considered crystals. This is, apparently, a consequence of the metallic nature of LMO, which leads to smearing of the nearest-neighbor Mn–O bond charge over the other bonds. Finally, we note that the local properties for STO, BTO, and PTO not that close to each other might be obtained if noncubic low-temperature phases are studied. It is especially important to consider the orthorhombic phase of LMO since in this phase LMO is no longer metallic.

WTAO population analysis can be made also using the Bloch functions found in the calculations with plane-wave basis (as was noted, the majority of modern computer codes for periodic systems calculations use this basis and the DFT Hamiltonian).

The results of chemical-bonding analysis for crystal MgO, performed via the conventional and WF schemes of population analysis, were compared in [592]. The MgO crystal is a good testing system for studying the accuracy of such methods, since on the one hand, the nature of chemical bonding in it is well known to be ionic, and on the other hand, some of the methods give contradictory results of chemical-bonding analysis in this crystal (see below and [585,593]).

The electronic structure for the MgO crystal was calculated in [592] both in the LCAO approximation and in the PW basis. In both cases the calculations were done by the density-functional theory (DFT) method in the local density approximation (LDA). The Monkhorst–Pack set of special points of BZ, which allows a convergence to be obtained (relating to extended special-points sets) in the calculations of electronic structure, was used in both cases. For the LCAO calculations, the Durand–Barthelat pseudopotential [468] was used. In the case of the PW calculations, the norm-conserving pseudopotential and a PW kinetic energy cutoff of 300 eV were used.

For construction of the WTAOs, the delta-functions were used as the weight functions in the variational functional (9.35). In this case, the variational procedure is equivalent to projecting the delta-functions onto the space of the states of chosen energy bands and demands a very low computational effort.

In both types of calculations the *s*- and *p*-bands of oxygen atoms form the four valence bands. The *s*-band of the Mg in the case of the LCAO basis is the highest possible (twelfth) conduction band. For the PW calculations, the lower 32 conduction bands were examined. This analysis showed that the *s*-band of the Mg atom in PW calculations is also located among high-energy conduction bands. If one considers more than 32 conduction bands, the location of the *s*-band of the Mg atom can only increase, which would not affect the results of the population analysis.

Table 9.14 Calculated atomic charges and covalences in MgO

Basis	Population analysis	Charge on Mg atom	Atomic covalence	
			Mg	O
LCAO	Mulliken	1.93	0.15	0.30
	Löwdin	1.54	0.88	1.13
PW	Mulliken	1.06	1.63	1.65
	Löwdin	0.90	1.90	1.89
LCAO	Nonorthogonal WTAOs	2.00	0.00	0.00
	Orthogonal WTAOs	1.97	0.05	0.05
PW	Nonorthogonal WTAOs	2.00	0.00	0.05
	Orthogonal WTAOs	1.93	0.13	0.14

The calculations [592] showed that the WTAOs, corresponding to the LCAO and PW bases, are essentially different in their form. This distinction is probably caused mainly by the difference in the structure of the bases used for the LCAO and PW calculations. All the WTAOs, excluding the *s*-WTAO of the Mg atom in the PW calculations, are well localized. The poor localization of the latter is probably due to considering only 32 lower bands, while the actual *s*-band of the Mg atom might lie higher in the energy than the examined ones. Anyway, the difference in the WTAOs' form and localization level does not affect the results of WTAO-based population analysis for MgO.

The atomic charges and covalences, calculated within the conventional approaches and WTAOs method, are given in Table 9.14.

The spilling parameter for the projection procedure (see Sect. 9.1.6) in the PW calculations was 2.5×10^{-3} . It is seen from this table that among the traditional schemes, only the Mulliken analysis performed for the LCAO calculations exhibits a more or less ionic picture of chemical bonding in MgO. All the other conventional methods give the results corresponding to the mixed ionic-covalent type of bonding, which is actually quite unnatural for MgO. Besides, for the traditional methods the values of the atomic charges and covalences are significantly different depending on the calculation scheme and the type of basis.

On the contrary, the method based on orthogonal or nonorthogonal WTAOs correctly demonstrates the ionic nature of chemical bonding in MgO crystal whatever basis is used for the electronic-structure calculations. The values obtained within the different types of basis are close and correspond to the practically pure ionic character of bonding in this crystal. Though the LDA band-structure calculations for the MgO crystal in LCAO and PW bases give different values for the total energy and bandgap width and the forms of corresponding WTAOs are quite dissimilar, nevertheless, the results of population analysis performed in the basis of WTAOs are practically the same. This is a consequence of a high-energy location of the *s*-band of the Mg atom in both types of calculations.

9.1.5 The Localized Wannier Functions for Valence Bands: Chemical Bonding in Crystalline Oxides

The approach to the analysis of the chemical bonding in crystals discussed above is based on the population-analysis procedure, applied in the basis of AOs or WTAOs. In the second approach [60] the Wannier functions are generated using the Bloch functions of only the upper valence bands (see Chap. 3), so that the number N_{WF} of WFs per primitive cell is equal to the number of valence bands under consideration. For metal oxides, considered in this section, the upper valence energy bands are formed by $2s$ and $2p$ states of oxygen atoms. Therefore, the number of WFs per cell $N_{WF} = 4N_f N_O$ (N_f is the number of formula units per cell, N_O is the number of oxygen atoms in the formula unit). In particular, $N_{WF} = 4, 24, 48$ for MgO , Al_2O_3 and $AlPO_4$ crystals with one, two and three formula units per cell, respectively. This approach provides the additional numerical characteristics of chemical bonding, which complement the population analysis in periodic systems.

Any of the WFs in the reference cell is given in the AO basis set (used in the Bloch-function calculation) as

$$W_i(\mathbf{r} - \mathbf{g}) = W_i(\mathbf{r}) = \sum_{\mu=1}^M \sum_{\mathbf{g}'} C_{\mu i}^{g'} \chi_{\mu}(\mathbf{r} - \mathbf{A}_{\mu} - \mathbf{g}') \quad (9.44)$$

where the orthonormality condition $\langle W_i^g | W_i^{g'} \rangle = \delta_{gg'}$ holds for the periodic images $W_i(\mathbf{r} - \mathbf{g})$ of the reference cell WF. The coefficients $C_{\mu i}^{g'}$ in (9.44) are related to the coefficients $C_{\mu i}(\mathbf{k}_j)$ in the Bloch functions of M valence bands by the relation

$$C_{\mu i}(\mathbf{k}_j) = \sum_{\mathbf{g}'} \exp(-i\mathbf{k}_j \mathbf{g}') C_{\mu i}^{g'} \quad (9.45)$$

In these relations $\mu = 1, 2, \dots, M$ numbers AOs in the primitive cell, $\mathbf{g}$ is the direct lattice translation vector, $i = 1, 2, \dots, N_{WF}$ numbers the valence bands and WFs and $\mathbf{k}_j$ ($j = 1, 2, \dots, L$) are defined by the size of cyclic system L used for the summation over BZ (see Chap. 3). WFs are characterized in terms of their Mulliken atomic populations by

$$q_{A,i}^g = \sum_{\mu \in A} \sum_{v, \mathbf{g}'} C_{\mu, i}^g C_{v i}^{g+g'} S_{\mu v}^{g'} \quad (9.46)$$

where the first sum runs over the AOs μ centered on atom A and the second one over all the AOs v and cells $\mathbf{g}'$. The atomic populations (9.46) are normalized to one, *that is*, they satisfy the condition $\sum_{A, \mathbf{g}} q_{A,i}^g = 1$. These populations are used to describe

the localization properties of WFs, as $q_{A,i}^g$ gives the fraction of the electron density of WF $W_i(\mathbf{r})$ assigned to atom A in cell $\mathbf{g}$. The range of WF $W_i(\mathbf{r})$ localization

is defined by nonzero values of (9.46) in spheres of atoms around the localization center of WF. The latter (centroid position) is defined by

$$\bar{\mathbf{r}}_i = \int \mathbf{r} |W_i(\mathbf{r})|^2 d\mathbf{r} = \sum_s \bar{x}_{si} \bar{e}_s, \bar{x}_{si} = \int x_s |W_i(\mathbf{r})|^2 d\mathbf{r} \quad (9.47)$$

The centroid positions are used in the definition of the second-order central moment tensor, $\tau_{i,lm}$ of the electron density associated to WF $W_i(\mathbf{r})$:

$$\tau_{i,lm} = \int d\mathbf{r} |W_i(\mathbf{r})|^2 (r_l - r_{i,l})(r_m - r_{i,m}) \quad (9.48)$$

where $\mathbf{r} = (r_1, r_2, r_3)$ and $\mathbf{r}_i = (r_{i1}, r_{i2}, r_{i3})$. Tensor (9.48) contains useful information on the shape and spatial extent of the WFs. Centroid position $\mathbf{r}_i$ of the WF $W_i(\mathbf{r})$ also determines the so-called polarization fraction for $W_i(\mathbf{r})$:

$$P_i = \left| 2 \frac{(\mathbf{r}_i - \mathbf{r}_A)(\mathbf{r}_B - \mathbf{r}_A)}{|\mathbf{r}_B - \mathbf{r}_A|^2} - 1 \right|, \quad (0 \leq P_i \leq 1) \quad (9.49)$$

which is proposed to estimate the degree of ionicity and covalency of the chemical bonding between atoms A and B ($\mathbf{r}_A$ and $\mathbf{r}_B$ are their position vectors). This parameter takes the value $P_i = 1$ for a pure ionic bond and $P_i = 0$ for a pure covalent bond. A and B atoms are supposed to give the two largest contributions of the Mulliken atomic population to the WF $W_i(\mathbf{r})$.

These indices were used to analyze the chemical bonding in semiconductors [594] and metal oxides [60], based on HF LCAO calculations. In Table 9.15 the results for metal oxides are presented. In this table N_f , N_{WF} and N_c are the number of formula units in the primitive cell, the number of valence-WFs in the primitive cell and the coordination number of the oxygen atom. According to the point symmetry at the O position, the four WFs can be equivalent, as in the case of MgO and MnO, or split into 2, 3, or 4 sets; the number of equivalent WFs in each set is indicated in the N_{eq} column. In those systems where crossings occur between the valence and the most diffuse semicore bands (the transition-metal oxides MnO and ZnO and CaSO₄) the cation d and the Ca $2p$ bands, respectively, have also been included within the active subspace. In MnO, where only the ferromagnetic spin polarized solution was considered, α and β subspaces are localized independently (the former conventionally containing the five Mn d states), [60]. In the right part of the table some features of the oxygen-WFs are provided: N_{eq} is the number of equivalent oxygen-WFs in the set; q_1 , q_2 and q_3 are the three largest Mulliken atomic populations (the number of equivalent contributions is given in brackets!). The Or column indicates whether the second-order moment tensor principal axis is oriented along the bond axis (y) or not (n), and the last column classifies the WFs as *covalent bond* (cv), *ionic* (io), or *lone pair* (lp). The degree of localization of the oxygen WFs is estimated in terms of the Mulliken atomic populations (9.46), attributed to oxygen and its neighboring atoms. These data are summarized in

Table 9.15 Characterization of the oxides through their symmetry and WF features [60] (explanations are given in text)

System	Space group	N_f	N_{WF}	N_c	N_{eq}	q_1	q_2	q_3	Or	Class
MgO	$Fm\bar{3}m$	1	4	6	4	0.991	0.005(2)	0.004	n	io
MnO- α	$Fm\bar{3}m$	1	9	6	4	1.005	-0.001(4)	—	n	io
MnO- β	—		4		4	0.969	0.016(2)	0.005	n	io
ZnO	$P6_3mc$	2	18	4	1	0.929	0.065(3)	0.002	y	cv
					3	0.927	0.065(3)	0.003	y	cv
Al ₂ O ₃	$R\bar{3}c$	2	24	4	2	0.964	0.043	0.004	y	cv
					2	0.942	0.060	0.003	y	cv
SiO ₂	$P3_121$	3	24	2	1	0.957	0.022	0.020	n	lp
					1	0.947	0.029	0.026	n	lp
					1	0.815	0.167	0.017	y	cv
					1	0.812	0.171	0.017	y	cv
AlPO ₄	$P3_121$	3	48	2	1	0.965	0.030	0.006	n	lp
					1	0.952	0.031	0.021	n	lp
					1	0.910	0.070	0.023	y	cv
					1	0.821	0.173	0.006	y	cv
CaSO ₄	$P6_222$	3	48	1	3	0.958	0.039	0.004	n	lp
					1	0.711	0.296	0.001	y	cv

columns q_1 , q_2 , and q_3 of Table 9.15. It turns out that, in all cases, most of the electron density is localized on the oxygen atom, q_1 ranging from 0.71 (CaSO₄) to 1.01 (MnO). The value of the second atomic contribution is never larger than 0.30 (CaSO₄); in most cases, however, it is of the order of 0.05. The third largest atomic population is much smaller and never exceeds 0.03 (SiO₂).

The Or column provides information as to whether the principal axis connected to the largest eigenvalue of the second-order moment tensor is oriented along the bond axis or not. The bond axis of an O–WF is defined as the line joining the oxygen and the atom that brings the second largest contribution to the total population. For ease of discussion, one can try to use the two kinds of information (q_i and Or indices) to classify (with a certain degree of arbitrariness) the O–WFs bonds as covalent bond (cv), lone pair (lp), or ionic (io). In particular, it is considered as cv, a WF oriented along the bond direction, (orientation criterion); alternatively, a WF can be classified as cv, when $q_1 < 0.95$ and $q_2 > 0.05$ (population criterion), where q_1 and q_2 are the two largest contributions to the total population (see Table 9.15). A non-cv-WF is classified as io or lp when the coordination number of O is larger or smaller than 4 (the number of WFs formally attributable to oxygen), respectively. As is shown in [60], io and lp WFs do have quite different characteristics. The two criteria provide a very consistent classification, the only exception being the most localized O–WFs of Al₂O₃, classified as cv or not according to the first or second criteria, respectively. Indeed in this case, both types of WFs are of the same chemical nature and quantitative differences are probably due to geometrical constraints. The orientation criterion seems to be the most appropriate and has been adopted (see last column of Table 9.15). This classification allows various trends to be traced

with respect to the nature of the O–WFs along the series of compounds, as was done in [60]. In particular, it turns out that WF's give quite a complete picture of the chemical nature of the X–O bond, indicating that the covalent character increases according to the following sequence with respect to X: $\text{Mg} < \text{Mn} < \text{Al} < \text{Zn} < \text{Si} < \text{P} < \text{S}$. This order coincides with the cation Pauling electronegativities and demonstrates the atomic nature dependence of the chemical bonding in crystals.

This approach was applied also in [595] in the comparative study of chemical bonding in SrTiO_3 and SrZrO_3 crystals. The results of these calculations are discussed in the next section in the consideration of the projection technique for population analysis in crystals.

The numerical values of the indices dependence on the basis-set choice requires additional investigation. It is evident that use of Löwdin atomic populations instead of Mulliken ones can change the localization of WF's, especially in the case when diffuse AOs are included in the basis set. From this point of view the WTAOs use is preferable. As was demonstrated above, the numerical values of local properties are close in Mulliken and Löwdin population analysis made with WTAOs.

In the approach [60] WF's are generated directly from Bloch valence states without any preliminary symmetry analysis. In this case one obtains WF's that have the centroid positions in the vicinities of some points of the direct lattice of the crystal occupied by atoms or being midpoint between the pairs of symmetry-equivalent atoms (for the oxides listed in Table 9.15, these points are near oxygen atom positions). The noncontradictory chemical interpretation of the WF's obtained is difficult due to the absence of the symmetry analysis. Indeed, it is difficult to explain the appearance in MgO crystal (see Table 9.15) of four equivalent WF's corresponding to the tetrahedral sp^3 hybridization, while the oxygen atom is octahedrally coordinated.

The improvements of this theory were suggested in [596]. The importance of the symmetry analysis in the procedure of the generation of maximally LOs in crystals was shown. It was suggested that the numerical parameters of the LOs corresponding to the valence energy bands of the crystal can be used in the theory of chemical bonding only if these functions form bases of irreducible representations of site-symmetry groups of atoms and bonds in crystals. The background of LOs symmetry analysis is the theory of band representations (BRs) of space groups, considered in Chap. 3. This analysis is applicable both to nonorthogonal atomic-like localized orbitals, centered on the atoms, and to localized Wannier orbitals (LWOs), *that is*, to an orthonormal set of LOs. BRs of space groups are used to identify possible LOs symmetry from the symmetry of the canonical (Bloch) orbitals of the calculated energy bands or to establish the fact that the construction of LOs from the canonical orbitals chosen is impossible for the reasons of symmetry. In the general case, the LWOs are centered on some center $\mathbf{q}$ and transform according to some representation Re (in the general case reducible) of the site-symmetry group $L_{\mathbf{q}}$ of this center. Let us represent these functions as linear combinations of the LWOs $\tilde{W}_j^{(\beta)}$ transforming according to IRs β of the site group $L_{\mathbf{q}}$,

$$W_i(\mathbf{r}) = \sum_{\beta,j} \alpha_{\beta j,i} \widetilde{W}_j^{(\beta)}(\mathbf{r}), \quad \alpha^T \alpha = E \quad (9.50)$$

The transformation, with the help of the matrix α , is orthogonal as it relates to two orthonormal bases in the space of the representation Re (E is the unit matrix). Inserting (9.50) in (9.47), one obtains

$$\bar{x}_{si} = \sum_{\beta\beta'jj'} D_{\beta j, \beta' j'}^{(s)} \alpha_{\beta j,i}^* \alpha_{\beta' j',i} \quad (9.51)$$

where the number of independent values $D_{\beta j, \beta' j'}^{(s)} = \langle \widetilde{W}_j^{(\beta)}(\mathbf{r}) | x_s | \widetilde{W}_{j'}^{(\beta')}(\mathbf{r}) \rangle$ is equal to the number of irreducible components of the vector representation contained in the symmetric square $\{Re \times Re^*\}^+$ of the representation Re [13]. If $W_i(\mathbf{r})$ coincide with their irreducible components ($\alpha_{\beta j,i} = \delta_{\beta j,i}$), then $\mathbf{r}_i = 0$ for centrosymmetric site groups L_q as all $D_{\beta j, \beta' j'}^{(s)} = 0$ ($\bar{x}_{si} = 0$). In the general case, as seen from (9.51), $\mathbf{r}_i \neq 0$ and their lengths and orientations depend on the value of the coefficients $\alpha_{\beta j,i}$. Being functions of the centroid position, the polarization fractions P_i (9.49) also depend on the value of the coefficients $\alpha_{\beta j,i}$. It is obvious that *in the general case one cannot attribute to the centroid of a LWO some physical meaning*. But a particular choice of LOs can attach to the centroid a common sense useful in the theory of chemical bonding.

LWOs $W_A(\mathbf{r})$ sited on atoms describe lone pairs or a purely ionic bonding ($P_i = 1$). LWOs $W_B(\mathbf{r})$ sited on interatomic bonds mean the presence of a covalent component of the chemical bonding ($0 < P_i < 1$), the degree of covalence being determined by the value of the polarization fraction P_i that takes the form

$$P_i = \left| 2 \frac{d_i - d_A}{d_B - d_A} - 1 \right| \quad (9.52)$$

where d_A, d_B , and d_i are positions of atoms A, B , and the centroid of the LWO $W_i(\mathbf{r})$ on the bond line $A - B$ counted off some arbitrary point on it. In the latter case, the BR associated with the valence bands of the crystal has to include the BR induced from some IR β of the site-symmetry group L_{q_b} of the bond. The value $P_i = 0$ corresponds to a pure covalent bond. Note that this BR is a composite one. Indeed, the group L_{q_b} is a subgroup of the site group L_{q_A} of the atom A (and of the site group L_{q_B} of the atom B) lying on the bond. The IR β induces in the groups L_{q_A} some reducible representation that, in its turn, induces in the space group G a composite BR [13]. There is an exception when a middle point of the bond is a symmetry point. In this case, the IR of the site group of this point induces in the space group G a simple BR. This situation takes place, for example, in the Si crystal where the IR a_{1g} of the site group D_{3d} of the middle point of the bond Si-Si (Wyckoff position c) induces in the space group O_h^7 of the crystal the BR with q -basis consisting of the canonical Bloch states of the four-sheeted upper valence band. This LWO describes the purely covalent bond ($P = 0$).

In [596] the following procedure was suggested to describe the chemical bonding in crystals by analyzing only occupied valence states in the basis of LOs.

As the first step a symmetry analysis of valence band states is carried out. The purpose of this analysis is to find the q -basis indices of the band representation (BR) corresponding to the valence states of the crystal. These indices can consist of: (a1) the irreducible representations (IRs) of the site groups of the bonds (including those of symmetry points on the bond lines, if there are any); (a2) the IRs of site groups of atoms. If a composite BR has several variants to be represented as a sum of simpler ones, the preference has to be given to the BRs induced from site groups of bonds. This symmetry analysis allows the centroid positions (on atoms or on bonds) of the LOs, generated from the Bloch functions of the valence states, to be found. The numerical characteristics of only these symmetry-defined LOs are suggested to give a noncontradictory unambiguous interpretation of chemical bonding in crystals. It was proposed in [596] to introduce not only the centroids position, but also the other numerical characteristics of the chemical bond related to the centroids position:

- (1) Contributions $Q_i^{(A)}$ and $Q_i^{(B)}$ to charges on atoms A and B related to the LO $W_i(\mathbf{r})$

$$Q_i^{(A)} = 2 \frac{d_i - d_B}{d_B - d_A}, \quad Q_i^{(B)} = 2 \frac{d_A - d_i}{d_B - d_A}, \quad -2 \leq Q_i^{(A)}, Q_i^{(B)} \leq 0 \quad (9.53)$$

An electron charge $Q_i^{(A)} + Q_i^{(B)} = -2$ associated with the fully occupied LO is partitioned between atoms A and B and is inversely proportional to the distances between the centroid position and the atoms.

- (2) The degree of ionicity I_i of the bond $A - B$ related to the LO $W_i(\mathbf{r})$,

$$I_i = \left| \frac{2d_i - d_A - d_B}{d_B - d_A} \right| = \frac{1}{2} \left| Q_i^{(A)} - Q_i^{(B)} \right|, \quad 0 \leq I_i \leq 1 \quad (9.54)$$

The degree of covalency K_i of the bond $A-B$ related to the LO $W_i(\mathbf{r})$,

$$K_i = 1 - \left| \frac{2d_i - d_A - d_B}{d_B - d_A} \right| = 1 - \frac{1}{2} \left| Q_i^{(A)} - Q_i^{(B)} \right|, \quad 0 \leq K_i \leq 1 \quad (9.55)$$

Ionicity I_i coincides with the polarization fraction (9.52).

For pure ionic bonding $Q_i^{(A)} = -2$, $Q_i^{(B)} = 0$ (or *vice versa*), $K = 0$, $I = 1$. For pure covalent bonding $Q_i^{(A)} = Q_i^{(B)} = -1$, $K = 1$, $I = 0$. The definitions (9.52)–(9.55) are introduced in such a way that the LWO centroid position defines the characteristics of chemical bonding. In fact, the details of the electron-density distribution have to be included, as is done in the definition (9.48) of the second-order central moment tensor.

In the second step of the chemical-bonding analysis the space Ω of the states of all the valence energy bands is projected on the spaces Ω_i of IR of the site-symmetry groups related to the components of the BR in the q -basis established above.

Table 9.16 Band representations of upper valence bands in the SrZrO₃ crystal induced from Sr 4*p*-, O 2*s*- and O 2*p*-atom-like states

Atom states	<i>q</i> -basis	Γ	<i>R</i>	<i>M</i>	<i>X</i>
Sr 4 <i>p</i>	(<i>b</i> , <i>t</i> _{1u})	4 ⁻	5 ⁺	2 ⁻ 5 ⁻	1 ⁺ 5 ⁺
O 2 <i>s</i>	(<i>d</i> , <i>a</i> _{1g})	1 ⁺ 3 ⁺	4 ⁻	1 ⁺ 5 ⁻	1 ⁺ 2 ⁺ 3 ⁻
O 2 <i>p_z</i>	(<i>d</i> , <i>a</i> _{2u})	4 ⁻	1 ⁺ 3 ⁺	1 ⁺ 2 ⁺ 3 ⁻	1 ⁺ 5 ⁻
O 2 <i>p_{x,y}</i>	(<i>d</i> , <i>e_u</i>)	4 ⁻ 5 ⁻	4 ⁺ 5 ⁺	3 ⁺ 4 ⁺ 5 [±]	3 ⁻ 4 ⁻ 5 [±]

The third step is the generation from the canonical Bloch valence states maximally localized orbitals in the spaces Ω_i by any known procedure.

The fourth step consists of calculation of numerical characteristics of the chemical bonding on the base of these LOs. This calculation includes both the characteristics, defined by the centroids positions, and those depending on the details of the electron-density distribution.

As follows from the theory of BR, the LOs obtained without any preliminary symmetry analysis, are in fact to be bases of some representations (in the general case reducible) of site-symmetry groups of the Wyckoff positions of atoms and bonds, the preference has to be given also to BRs induced from site groups of bonds. In this case, steps 2 and 3 have to be replaced by: (2a) Generation maximally LOs in the space of the canonical Bloch valence states by any known procedure. (3a) A proper symmetrization of generated LOs according to the results of the symmetry analysis of step 1.

We shall illustrate the discussed procedure using the example of the SrZrO₃ crystal with the cubic perovskite structure. In Table 9.16 band representations of space group O_h^1 induced by those atomic states that take part in the valence band formation are given. Each line of this table defines the connection of the *q*-basis for site-symmetry groups O_h (Sr), D_{4h} (O) with the *k*-basis at the symmetry points of BZ, see also Sect. 3.3.

To include the electron correlation effects on the chemical bonding, the calculations of SrZrO₃ crystal [596, 597] were performed by the DFT LCAO method with the CRYSTAL03 code [21] and the PBE exchange-correlation potential used in [598] for the geometry optimization in the generalized gradient approximation (GGA). For the Sr and Zr atoms, the Hay–Wadt pseudopotentials [467] in the small-core approximation were used. In this case, the 4*s*, 4*p*, and 5*s* states of the Sr atom in the 4*s*²4*p*⁶5*s*² configuration and the 4*s*, 4*p*, 4*d*, and 5*s* states of the Zr atom in the 4*s*²4*p*⁶4*d*²5*s*² configuration were treated as valence states. The basis functions were taken as the atomic functions of the Sr atom from [590] and the 8-411G * functions obtained for the Zr atom in [599] with optimization of the 5*sp*, 6*sp*, and 5*d* outer orbitals for the ZrO₂ crystal with experimental geometric parameters. For the oxygen atom, the full-electron basis set [590] describing the oxygen atom in the 1*s*²2*s*²2*p*⁴ configuration was used. The Monkhorst–Pack 8 × 8 × 8 set of special points was used in the BZ sampling. The lower valence bands are composed of Sr 4*p*- and O 2*s*-states (six sheets), whereas the upper valence band is produced mainly by the O 2*p*-atomic orbitals (nine sheets), see Fig. 9.2. The symmetry of all

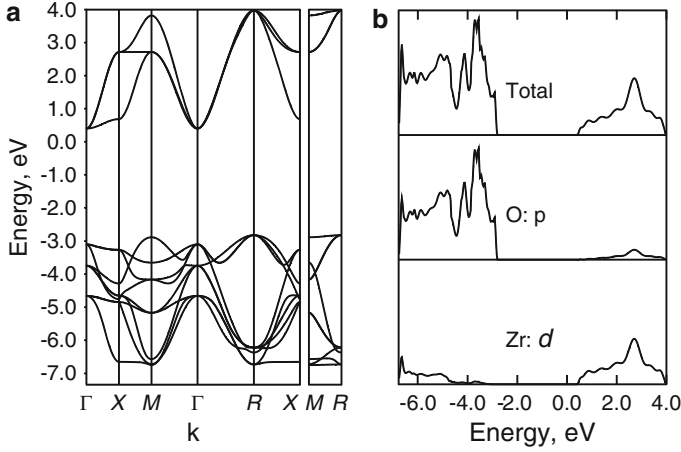


Fig. 9.2 Electronic structure of SrZrO₃ crystal: (a) band structure; (b) total and projected DOS. LCAO DFT calculations [597]

these valence-band states and the atomic nature of the projected density of states is the same both in these DFT LCAO and in former DFT PW calculations [600]. The iterative procedure implemented in CRYSTAL03 code was applied to generate LOs using crystal orbitals of these 15 occupied bands. The Bloch functions for the Γ point of the BZ are taken as the starting LOs. As a result, the iterative procedure gives 15 LOs. Three of them are centered on the Sr atom and are connected with Sr atom $4p$ -states. The remaining 12 LOs are connected with the three symmetry-equivalent oxygen atoms in the crystal, four LOs with the centroid positions near each oxygen atom. To analyze the nature of chemical bonding with these LOs, the information about the symmetry of the band states induced from Sr $4p$ -, O $2s$ -, and O $2p$ -states forming two upper valence bands given in Table 9.16 is used. It is seen that these states form a basis of composite BR described in q -basis by the symbol

$$(b, t_{1u}) + (d, a_{1g} + a_{2u} + e_u) \quad (9.56)$$

Therefore, four LWOs $W_i(\mathbf{r})$ with the centroid positions near each oxygen atom form a basis of a four-dimensional representation $a_{1g} + a_{2u} + e_u$ of the site group D_{4h} of the oxygen atom. Let us denote LOs that are the basis functions of these IRs as follows: $\tilde{W}_1(\mathbf{r}) = \tilde{W}_1^{(d, e_u)}(\mathbf{r})$, $\tilde{W}_2(\mathbf{r}) = \tilde{W}_2^{(d, e_u)}(\mathbf{r})$, $\tilde{W}_3(\mathbf{r}) = \tilde{W}_3^{(d, a_{2u})}(\mathbf{r})$, $\tilde{W}_4(\mathbf{r}) = \tilde{W}_4^{(d, a_{1g})}(\mathbf{r})$. Then, instead of (9.50), one has

$$W_i(\mathbf{r}) = \sum_{j=1}^4 \alpha_{ji} \tilde{W}_j(\mathbf{r}), \quad i = 1, 2, 3, 4 \quad (9.57)$$

Table 9.17 Centroids positions (x_{1i}, x_{2i}, x_{3i}) , in a.u., and polarization fractions p_i for functions $W_i(\mathbf{r})$ in the SrZrO_3 crystal localized according to the Wannier–Boys mixed scheme [60]

W_i	x_{1i}	x_{2i}	x_{3i}	p_i
W_1	−0.039	0.465	−0.002	0.999
W_2	0.465	−0.039	−0.002	0.999
W_3	−0.211	−0.211	0.774	0.610
W_4	−0.215	−0.215	−0.769	0.612

The starting LWOs of the computer code [21] result in $W_i(\mathbf{r})$ (9.57) with some definite values of the coefficients α_{ji} . In this case, $Re = e_u + a_{2u} + a_{1g}$, the representation $\{Re \times Re^*\}^{(+)} = 3a_{1g} + b_{1g} + b_{2g} + e_g + e_u + a_{2u}$ contains only one times two irreducible components of the vector representation $(e_u + a_{2u})$, that is, there are only two independent parameters in (9.51),

$$\bar{r}_i = \sum_{s=1}^3 \bar{x}_{si} \bar{e}_s, \quad \bar{x}_{si} = D_s \alpha_{4i} \alpha_{si} \quad (9.58)$$

where

$$D_1 = 2\langle \widetilde{W}_4(\mathbf{r}) | x_1 | \widetilde{W}_1(\mathbf{r}) \rangle = D_2 = 2\langle \widetilde{W}_4(\mathbf{r}) | x_2 | \widetilde{W}_2(\mathbf{r}) \rangle, \quad D_3 = 2\langle \widetilde{W}_4(\mathbf{r}) | x_3 | \widetilde{W}_3(\mathbf{r}) \rangle \quad (9.59)$$

In Table 9.17 the Cartesian coordinates $\bar{x}_{si}$ of centroid positions and the polarization fractions P_i for LWOs $W_i(\mathbf{r})$ evaluated by the computer code [21] are given. It is evident (see (9.58)) that the other choice of the starting LWOs can, in principle, give other centroid positions and other values of P_i . Let us note that the BR $(d, a_{1g} + a_{2u})$ is a composite one. The points on the line binding Zr and O atoms (Wyckoff position e) have the site-symmetry C_{4v} . The IR a_1 of this group induces in the group D_{4h} (the site-symmetry group of the oxygen atom) the representation $a_{1g} + a_{2u} : a_1(C_{4v}) \uparrow D_{4h} = a_{1g} + a_{2u}(D_{4h})$. Therefore, instead of (9.56) one can write another symbol in $\mathbf{q}$ -basis

$$(b, t_{1u}) + (d, e_u) + (e, a_1) \quad (9.60)$$

for the same BR corresponding to the 15-sheeted band chosen. Note that the IR a_1 of C_{4v} induces also the representation $a_{1g} + e_g + t_{1u}$ of the site group O_h of the Zr atom—the second atom on the bond line Zr–O: $a_1(C_{4v}) \uparrow O_h = a_{1g} + e_u + t_{1u}(O_h)$. Thus, one can attribute one more symbol in the $\mathbf{q}$ -basis to the BR corresponding to the same 15-sheeted energy band,

$$(b, t_{1u}) + (d, e_u) + (a, a_{1g} + e_g + t_{1u}) \quad (9.61)$$

It is seen that the part $(b, t_{1u}) + (d, e_u)$ is common for three symbols (9.56)–(9.60)–(9.61) of the BR under consideration. They correspond to LWOs, localized on Sr and oxygen atoms. The rest of the BR is given in three different ways by its labels (9.56)–(9.60)–(9.61). The symmetry considerations show that it is

possible to generate from the states of valence bands of the SrZrO_3 crystal the LWOs centered on zirconium and on oxygen atoms. These LWOs form the bases of reducible representations of the site groups of Zr and O atoms, $a_{1g} + e_g + t_{1u}$ of O_h and $a_{1g} + a_{2u}$ of D_{4h} , respectively. Linear combinations of functions of any of these bases are equivalent from the group-theoretical point of view, but will give *different* values for the numerical characteristics of chemical bonding (9.52)–(9.55). However, there is only *one* possibility to reconcile these two bases. Both bases are induced from the same IR a_1 of the common subgroup C_{4v} (the site group of the Wyckoff position e on the bond line Zr–O) of the groups O_h and D_{4h} .

The BR with $\mathbf{q}$ -basis (9.60) corresponds to a particular choice of the linear combinations of $\tilde{W}_j(\mathbf{r})$ (9.57): two of them are transformed according to the IR e_u of the site group (D_{4h}) of the oxygen atom, the linear combination $\tilde{W}_+^{(e,a_1)} = \frac{1}{\sqrt{2}} (\tilde{W}^{(d,a_{1g})} + \tilde{W}^{(d,a_{2u})})$ of two others engenders the LWO sited on the bond line Zr–O and transforming according to IR a_1 of the symmetry group C_{4v} of the bond. This LWO induces another one $\tilde{W}_-^{(e,a_1)} = \frac{1}{\sqrt{2}} (\tilde{W}^{(d,a_{1g})} - \tilde{W}^{(d,a_{2u})})$ centered on the Zr–O bonding line but at the other side of the same oxygen atom. On the whole, the number of LWOs per unit cell remains the same. These functions describe the covalent bonding of the oxygen atom with its two neighboring Zr atoms. The numerical value of covalency can be evaluated from the centroid positions of these LWOs counted off the oxygen atom.

To find the centroid positions of the LWOs $\tilde{W}_i(\mathbf{r})$ it is sufficient to symmetrize the LWOs $\tilde{W}_i(\mathbf{r})$ calculated without symmetry by the usual group-theoretical methods. Instead of extracting the LWOs themselves from the results of computer code [21] application it was done in [596] by using the relation (9.58) with the normality condition and the orthogonality of the matrix α in (9.58) connecting the symmetrized LWOs and those found in the direct calculations. This matrix was found in numerical form and analyzed in [596]. It was found that LWOs $\tilde{W}_i(\mathbf{r})$, $i = 1, 2$ almost coincide with $\tilde{W}_i^{(d,e_u)}(\mathbf{r})$ although they have a noticeable admixture of LWO $\tilde{W}^{(d,a_{1g})}(\mathbf{r})$. LWOs $\tilde{W}_i(\mathbf{r})$, $i = 3, 4$ are formed essentially by $\tilde{W}^{(d,a_{2u})}(\mathbf{r})$ and $\tilde{W}^{(d,a_{1g})}(\mathbf{r})$ although they have a noticeable admixture of LWO $\tilde{W}^{(d,e_u)}(\mathbf{r})$. Using (9.59), one obtains $\langle \tilde{W}^{(d,a_g)}(\mathbf{r}) | x_3 | \tilde{W}^{(d,a_{2u})}(\mathbf{r}) \rangle = 0.912$. The centroid positions relative to oxygen atoms for the LWOs $\tilde{W}_i(\mathbf{r})$ ($i = 1, 2, 3, 4$), $\mathbf{r} - \mathbf{r}_0 =$ and the corresponding polarization fraction $P_i = 1$ for all four LWOs. In particular, for $\tilde{W}_1^{(d,e_u)}(\mathbf{r})$ and $\tilde{W}_2^{(d,e_u)}(\mathbf{r})$, $P = 1$. They describe lone pairs on the oxygen atom in the crystal. But for the linear combinations $\tilde{W}_\pm^{(e,a_1)}(\mathbf{r})$ (the IR a_1 of the site group C_{4v} of the Wyckoff position e on the bond line Zr–O), $\mathbf{r}_\pm - \mathbf{r}_0 = \pm 0.912e_3$ (in a.u.) and the polarization fractions $P_\pm = 0.54$. These LWOs describe the partly covalent binding of atoms O and Zr in the crystal SrZrO_3 . The other numerical characteristics (9.53) and (9.54) of this bond are: $Q^{(O)} = -1.54$, $Q^{(\text{Zr})} = -0.46$, $I_{\text{O-Zr}} = 0.54$, $K_{\text{O-Zr}} = 0.46$. Taking into account the choice of valence and semicore electrons, atomic cores have the charges: $+6(\text{O})$, $+8(\text{Sr})$, $+4(\text{Zr})$. According to the $\mathbf{q}$ -basis index of the BR (9.60) the electron structure of the crystal can be represented by 15 LWOs per primitive cell, every orbital being occupied by two electrons:

1. Three orbitals $\tilde{W}^{(b,t_{1u})}(\mathbf{r})$ of symmetry t_{1u} (p -type) are localized on Sr (site group O_h) and bring to it the charge -6 . Finally, atom Sr has in the crystal the charge $+2 = 8 - 6$ rigorously. This value is close to that found by population analysis with WTAOs.
2. Six orbitals $\tilde{W}^{(d,e_u)}(\mathbf{r})$ of symmetry e_u (p_x, p_y -type) are localized on O atoms (site group D_{4h} , three atoms per primitive cell) and bring to every atom the charge -4 .
3. Six orbitals $\tilde{W}^{(e,a_1)}(\mathbf{r})$ of symmetry a_1 (sp_z -type) are localized on the bonding line O–Zr (site group C_{4v} , six bonding lines per primitive cell). The charge -2 associated with every orbital is partitioned between oxygen (-1.54) and zirconium (-0.46) atoms. As there are two bonds for the oxygen atom, its charge in the crystal is $-1.08 (= +6 - 4 - 1.54 \times 2)$. Equally for the zirconium atom, one has $+1.24 (= +4 - 0.46 \times 6; 6 \text{ bonds for Zr})$. The traditional Mulliken population analysis gives values -1.29 and $+2.02$, the projection techniques -1.14 and $+1.63$, WTAO population analysis gives more ionic charges $-1.67 + 3.00$, [595].

Using the symmetry analysis in MgO crystal [596] for the Bloch states of the four upper valence bands one obtains the $\mathbf{q}$ -basis of symmetry

$$(a, a_{1g} + t_{1u}) \quad (9.62)$$

with the oxygen atom in the Wyckoff position a. Electronic states of these energy bands are originated certainly from $2s, 2p$ -O atomic states. The points on the bond line of the atoms Mg and O (Wyckoff position e) have the symmetry C_{4v} . Even the one-dimensional IR a_1 of this group induces in the group O_h the six-dimensional representation $a_1(C_{4v}) \uparrow O_h = a_{1g} + e_g + t_{1u}(O_h)$. This means that there exists no LWO centered on this bond that could generate a four-sheeted upper valence energy band in the MgO crystal. One can say the same about the LWOs centered on the Wyckoff position $f(x, x, x)$ with site group C_{3v} : they could engender an eight-sheeted energy band.

Therefore, there is no other alternative but (9.62) for the BR corresponding to valence bands in the MgO crystal. For a reasonable interpretation of bonding in the crystal only the functions $\tilde{W}_1(\mathbf{r}) = \tilde{W}^{(a,a_{1g})}(\mathbf{r})$, $\tilde{W}_i(\mathbf{r}) = \tilde{W}_1^{(a,t_{1u})}(\mathbf{r})$, $i = 2, 3, 4$ are suited. They are centered on an oxygen atom and $\mathbf{r}_i = \mathbf{r}_O$, $Q_i^{(0)} = -2$, $I_i = P_i = 1$, $K_i = 0$ ($i = 1, 2, 3, 4$). The centroid positions and the values of other numerical characteristics of chemical bonding are not changed evidently for any linear combination of the functions $\tilde{W}_i(\mathbf{r})$, $i = 1, 2, 3, 4$ in the space of IR t_{1u} . The charges on atoms are: $+2(\text{Mg})$, $-2(\text{O})$ strongly. Such a picture of chemical bonding in MgO crystal corresponds to the accepted one for this ionic system. Nevertheless, it is necessary to introduce such numerical characteristics of LWOs that could describe the small covalent part of Mg–O bonding and relative change of this part in the row MgO–CaO–SrO–BaO.

This discussion demonstrates the importance of the symmetry analysis in the procedure of the generation of LWOs in crystals. The theory of space group BR gives a powerful tool to determine the centroid positions of LWOs.

- (1) If this centroid is at the symmetry point in the direct lattice, its position is defined exactly by the BR theory. If this position is occupied by an atom, the corresponding LWO describes an ionic bond or a lone pair. This is the case for the MgO crystal and the LWOs $\tilde{W}_1^{(d,e_u)}$ and $\tilde{W}_2^{(d,e_u)}$ in the SrZrO₃ crystal. If it is a middle point between two atoms, the corresponding LWO describes a pure covalent bond. This is the well-known example of the Si crystal.
- (2) If the centroid is located on a symmetry line (possible site groups are $C_{6v}, C_{4v}, C_{3v}, C_{2v}, C_6, C_4, C_3, C_2$), its exact position cannot be defined by the BR theory, and numerical calculations are necessary. The corresponding LWO describes a two-atom partly covalent bond. This is the case of the LWO $\tilde{W}^{(e,a_1)}$ (site group C_{4v}) in the SrZrO₃ crystal with the following numerical characteristics of the bond:

$$I_{O-Zr} = P_{O-Zr} = 0.54, K_{O-Zr} = 0.46, Q^{(O)} = -1.54, Q^{(Zr)} = -0.46$$

- (3) If the centroid is located at a symmetry plane (possible site group is C_s), its exact position cannot be defined by the BR theory, and numerical calculations are also necessary. The corresponding LWO describes a three-(and more)-atom bond.

As we saw in the example of SrZrO₃ crystal the absolute atomic-charge values differ in the different approaches to their calculation. Do different approaches (including those based on PW calculations) reproduce correctly at least the relative changes in the chemical bonding in crystals with analogous structure? This point is discussed in the next section.

9.1.6 Projection Technique for Population Analysis of Atomic Orbitals: Comparison of Different Methods of the Chemical-Bonding Description in Crystals

At present, the electronic structure of crystals, for the most part, has been calculated using the density-functional theory in a plane-wave (PW) basis set. The one-electron Bloch functions (crystal orbitals) calculated in the PW basis set are delocalized over the crystal and do not allow one to calculate the local characteristics of the electronic structure. As a consequence, the functions of the minimal valence basis set for atoms in the crystal should be constructed from the aforementioned Bloch functions. There exist several approaches to this problem. The most consistent approach was considered above and is associated with the variational method for constructing the Wannier-type atomic orbitals (WTAO) localized at atoms with the use of the calculated Bloch functions. Another two approaches use the so-called projection technique to connect the calculated in PW basis Bloch states with the atomic-like orbitals of the minimal basis set.

The first approach (A) consists in using the technique for projecting the Bloch functions calculated in the PW basis set onto atomic orbitals of the minimal valence basis set for free atoms [601, 602]. Within this procedure the atomic-like functions are generated using the pseudopotentials chosen for the PW band-structure calculations. Such functions are neither orthonormal nor complete in the sense of spanning the space of the occupied states. To measure how completely the localized atomic orbitals represent the eigenstates a so-called spilling parameter is introduced, which varies between one and zero. If the spilling parameter is nonzero a special projection procedure is needed to correctly define the density operator for the incomplete basis of atomic-like functions. Since this constructed localized basis is not orthogonal, as in the case of LCAO calculations both Mulliken and Löwdin schemes may be used.

The second approach (B), proposed for constructing quasiatomic minimal basis orbitals (QUAMBO) in [593] is also closely related to the projection technique (being in fact a projection reverse to the first one): the projection of a given minimal atomic basis is made on the Bloch states obtained in the PW calculations. This method can be regarded as a sort of localization procedure, and it describes the electronic structure of periodic solids in terms of localized quasiatomic minimal basis orbitals (QUAMBO).

Both variants of the projection technique were used for calculations of the local characteristics in the bulk of crystals [585, 593, 602] and, in a number of cases, led to results that are rather difficult to explain from the chemical standpoint. For example, the calculated charge of Mg atom in the ionic crystal MgO equals 0.76 [585]. Note that the construction of the WTAOs from the Bloch functions obtained in the PW basis set permitted almost ionic charges at atoms in the MgO crystal to be derived, see Table 9.14. However, it should also be noted that comparison of the data available in the literature on different characteristics obtained by the projection technique is complicated because the crystal orbitals are calculated with different variants of the DFT method, different pseudopotentials for excluding the core electrons from consideration, different atomic basis sets, etc. In order to interpret the results obtained by the projection technique, it is necessary to perform a comparative analysis of the density matrices (in the atomic orbital basis set) determined by the two aforementioned projection variants. In [603] such an analysis is carried out for the first time, and a simplified version of technique B was proposed to avoid cumbersome calculations of a large number of vacant crystal orbitals. Thus, in both variants A and B of the projection technique when the atomic orbital set for free atoms or free ions is assumed to be known, the population analysis can be carried out without invoking vacant crystal orbitals. We refer the reader for the mathematical details of this analysis to the publications [595, 603]. Here, we discuss only the numerical results, obtained in these studies for the local properties of electronic structure of crystals in both projection techniques and compare them with those obtained in traditional AO and WTAO Mulliken population analysis, including Bloch functions of vacant states. The comparison is also made with the results obtained with localized Wannier functions, generated only for the valence bands by method [60].

Table 9.18 Local properties of electronic structure in projection technique, [603]

Crystal	R_0	Q_A		C_A		spl (10^{-3})		W_{AB}		R_{AB}	
		A	B	A	B	A	B	A	B	A	B
MgO	2.107	1.609	1.607	0.630	0.632	1.4	1.1	0.112	0.113	0.095	0.096
BN	1.565	0.681	0.715	3.292	3.263	3.7	3.0	0.804	0.800	0.709	0.700
TiO ₂	1.951	1.730	1.739	3.474	3.459	2.2	1.4	0.552	0.550	0.305	0.302
Si	2.364	0.000	0.000	3.823	3.801	9.6	6.5	0.894	0.889	0.756	0.744
SiC	1.901	1.260	1.284	3.497	3.472	8.9	5.3	0.831	0.827	0.760	0.751
GaAs	2.451	0.361	0.380	3.231	3.202	1.8	1.8	0.768	0.765	0.636	0.629

In Table 9.18 we give the local properties of electronic structure (atomic charges Q_A , covalences C_A , bond orders W_{AB} and overlap populations R_{AB}) calculated by projection techniques A and B for the crystals with different nature of chemical bonding: Si, SiC, GaAs, MgO, cubic BN, and TiO₂ with a rutile structure, R_0 is the nearest-neighbor distance, given in Å.

The crystal orbitals were calculated by the DFT method in the plane-wave basis set with the CASTEP code [365] in the GGA density functional. A set of special points k in the Brillouin zone for all the crystals was generated by the supercell method (see Chap. 3) with a $5 \times 5 \times 5$ diagonal symmetric extension, which corresponds to 125 points. In all cases, the pseudopotentials were represented by the norm-conserving-optimized atomic pseudopotentials [605], which were also used to calculate the atomic potentials of free atoms. In the framework of both techniques (A, B), the population analysis was performed in the minimal atomic basis set; *that is*, the basis set involved only occupied or partially occupied atomic orbitals of free atoms. It is well known that the inclusion of diffuse vacant atomic orbitals in the basis set can substantially change the results of the population analysis. For example, if the Mg $2p$ vacant atomic orbitals are included in the basis set, the charge calculated by technique A for the Mg atom in the MgO crystal decreases from 1.61 to 1.06. Consequently, the inclusion of the Mg $2p$ functions leads to a considerable decrease in the ionic component of the bonding and, correspondingly, to an increase in the covalence of atoms. Chemically, it is difficult to explain this high covalency of the bonding in the MgO crystal.

The spilling parameter spl values are also given in Table 9.18, which characterize the accuracy of the projection of occupied crystal orbitals onto the space of the atomic orbitals (technique A) and the accuracy of the projection of atomic orbitals onto the Bloch functions (technique B).

The atomic charges obtained by technique A can be compared with those calculated in [585] with the use of a similar method. The atomic charges and the spilling parameters presented in [585] are considerably smaller than those in the calculation discussed. In our opinion, the main factor responsible for this disagreement is the difference between the atomic basis sets that are used for the projection. This assumption is confirmed by the following fact noted in [585]. The removal of the Si d vacant orbital from the atomic basis set leads to an increase in the charge at the Si atom in the SiC crystal from 0.66 to 1.25 and an increase in

Table 9.19 Local characteristics of the electronic structure of the TiO₂ (rutile) crystal^a

Method	Q_{Ti}	C_{Ti}	$W_{\text{Ti-O}}$	V_{Ti}
A	1.79	3.36	0.51	4.13
B	1.80	3.34	0.51	4.12
LCAOM	1.78	3.30	0.52	4.08
LCAOL	1.04	4.29	0.66	4.52
WTAOM	1.98	3.16	0.51	4.11
WTAOL	1.92	3.23	0.52	4.12

^a LCAOM(L)—traditional Mulliken (Löwdin) population analysis with basis set used in LCAO calculations; WTAOM(L)—Mulliken (Löwdin) population analysis with WTAO basis set

the spilling parameter from 2×10^{-3} to 9×10^{-3} . It follows from Table 9.18 that, in calculations in the minimal basis set (without the Si d function), these quantities are equal to 1.26×10^{-3} and 8.9×10^{-3} , respectively, which agrees well with the results obtained in [585] (without the Si d function). It is evident that an increase in the size of the basis sets should result in a decrease in the spilling factor in method A, because this is accompanied by an increase in the space of the atomic orbitals onto which the occupied crystal orbitals are projected. However, we believe that it is incorrect to decrease the spilling parameter in the population analysis of the atomic orbitals by increasing the atomic basis sets, as was actually done in [585]. For example, if the basis set of the atomic orbitals is increased to a complete set, the spilling coefficient can be reduced to zero; however, the population analysis of the atomic orbitals in this basis set loses all physical meaning.

For the purely covalent cubic Si crystal, the results obtained by technique B can be compared with the data reported in [593], for Si–Si bond order $W_{AB} = 0.885$ and the Mulliken overlap population is $R_{AB} = 0.756$. As can be seen from Table 9.18, the results obtained by technique B ($W_{AB} = 0.889$, $R_{AB} = 0.744$) are very close to those given in [593]. The insignificant differences can be associated with the use of different variants of the DFT method in the plane-wave basis set. Note that technique B used in [603] is a simpler modified variant of the method proposed in [593] and does not deal with the vacant Bloch states.

It can be seen from Table 9.18 that the data calculated by the techniques A and B are in good agreement. It should only be noted that the ionic component of the bonding (Q_A) in technique B is somewhat larger than the analogous component in technique A. Correspondingly, the covalent component (C_A , W_{AB} , R_{AB}) is somewhat smaller in technique B. Moreover, the spilling parameters in technique B are regularly smaller in magnitude.

In Table 9.19 we compare the local characteristics of the electronic structure determined for the TiO₂ crystal with the use of the projection technique and those obtained in an earlier study [607], in which the Wannier-type atomic functions of the minimal valence basis set of titanium and oxygen atoms were constructed by the variational method. In [607], the Bloch functions were calculated by the DFT method in the LCAO approximation with the CRYSTAL code [21] and the atomic pseudopotentials taken from [468]. It follows from Table 9.19 that the local

Table 9.20 Local properties of electronic structure of SrMO₃ crystals (M=Ti, Zr) in Mulliken population analysis, projection techniques and WTAO population analysis [595]

Quantity	Mulliken		Projection A		Projection B		WTAO	
	LCAO		PW		PW		LCAO	
	SrTiO ₃	SrZrO ₃	SrTiO ₃	SrZrO ₃	SrTiO ₃	SrZrO ₃	SrTiO ₃	SrZrO ₃
$Q(\text{Sr})$	1.85	1.85	1.83	1.80	1.83	1.80	2.00	2.00
$Q(\text{M})$	2.24	2.02	1.46	1.63	1.46	1.63	2.54	3.00
$Q(\text{O})$	-1.36	-1.29	-1.09	-1.14	-1.09	-1.14	-1.51	-1.67
$W_{\text{Sr-O}}$	0.036	0.033	0.025	0.026	0.026	0.027	0.00	0.00
$W_{\text{M-O}}$	0.461	0.496	0.626	0.607	0.663	0.606	0.389	0.269

characteristics of the electronic structure of the TiO₂ crystal are close for two projection variants (techniques A, B) and differ only slightly from the results of the Mulliken (not Löwdin!) population analysis performed in the basis set of the atomic orbitals at the LCAO level. It is seen that the traditional Löwdin population analysis with the initial LCAO basis set containing diffuse atomic functions leads to an overestimated covalence of chemical bonding.

When analyzing the populations in the WTAO basis set, the Löwdin orthogonalization of the basis set leads to insignificant differences as compared to the results of the Mulliken population analysis (due to the localized character of the Wannier-type atomic functions). The Löwdin atomic charges and the atomic covalences correspond to a somewhat lower degree of ionicity. An important conclusion can be drawn from comparison of WTAO results with those obtained in the projection technique: despite the use of substantially different basis sets for calculating the crystal orbitals (plane waves in the projection technique, LCAO in the WTAO method), the local characteristics of the rutile electronic structure obtained within the two approaches are in good agreement. Meanwhile, the results of traditional population analysis differ from those obtained by the projection technique (see Table 9.19). This difference is demonstrated also in Table 9.20, where for SrTiO₃ and SrZrO₃ crystals the results of traditional Mulliken population analysis are compared with those obtained by the projection technique (both crystals were taken in cubic perovskite structure with the space group $Pm\bar{3}m$).

The results, given in Table 9.20, were obtained by the DFT PBE method in LCAO and PW calculations (the details of the LCAO basis set and other parameters choice can be found in [595]). In the projection technique the atomic orbitals were numerically calculated for occupied states of free atoms using the same pseudopotentials as in the PW band-structure computations. As can be seen in Table 9.20, the results of projection-techniques application, unlike the traditional population analysis, exhibit the correct trends in the chemical-bonding change when the Ti atom is replaced by the Zr atom in the same structure (the experimental lattice constants were used for both cases). The population analysis based on the projection technique shows that ionicity of chemical bonds M–O (M = Ti, Zr) in SrZrO₃ is larger than in SrTiO₃. This is in agreement with the experimental data

Table 9.21 Localization indices of localized Wannier functions in SrTiO₃ and SrZrO₃ crystals [595]

Crystal	LWF $W_i(\mathbf{r})$	λ_i	p_i	q_O	q_{Os}	q_{Op_x}	q_{Op_y}	q_{Op_z}
SrTiO ₃	a ($i=1$)	1.145	0.978	0.934	0.191	0.731	0.011	0.002
	b ($i=2$)	1.145	0.978	0.934	0.191	0.011	0.731	0.002
	c ($i=3$)	1.252	0.627	0.890	0.311	0.064	0.064	0.453
	d ($i=4$)	1.230	0.670	0.890	0.296	0.117	0.117	0.373
SrZrO ₃	e ($i=1$)	1.183	0.999	0.918	0.136	0.005	0.778	0.000
	f ($i=2$)	1.183	0.999	0.918	0.136	0.778	0.005	0.000
	g ($i=3$)	1.302	0.610	0.870	0.343	0.064	0.064	0.403
	h ($i=4$)	1.300	0.610	0.870	0.341	0.066	0.066	0.400

on the bandgaps in SrTiO₃ (3.2 eV) and SrZrO₃ (5.9 eV) and the relative Pauling electronegativities of Ti (1.4) and Zr (1.2) atoms. Both variants of the projection approach give very close results for the local properties of electronic structure, possibly because the projection method A produces almost orthogonal crystalline orbitals. From Table 9.20 one can conclude that the traditional Mulliken population analysis within the framework of LCAO calculations does not correctly reproduce the relative ionicity of chemical bonding in SrTiO₃ and SrZrO₃ crystals, while the WTAO-based populations and projection-techniques application allows one to reflect properly the more ionic nature of SrZrO₃ in comparison with SrTiO₃.

Table 9.21 gives the localization indices of Wannier functions in SrTiO₃ and SrZrO₃ crystals calculated for the valence bands by the method used in [60].

Localized Wannier functions (LWFs) have been calculated for three upper valence bands in SrTiO₃ and SrZrO₃, represented mainly by O 2*p*, Sr 4*p*, and O 2*s* atomic states (in the case of SrZrO₃ the last two bands overlap considerably). A total of 15 crystalline orbitals have been used to generate, correspondingly, 15 LWFs per primitive unit cell: in both crystals under consideration, three oxygen atoms occupy the same Wyckoff positions, and four LWFs can be attributed to each oxygen atom. It was found by calculations with CRYSTAL03 code [21] that the centroids of four functions are positioned near the center of one oxygen (at distances of about 0.3 Å). Table 9.21 presents the following localization indices: the Mulliken population of LWF (9.46) q_O due to the oxygen atom and corresponding contributions from 2*s* and 2*p*-oxygen functions. The atomic delocalization index of LWF

$$\lambda_i = \left[\sum_A \sum_g (q_{Ai}^g)^2 \right]^{-1} \quad (9.63)$$

is a measure of the extent of the LWF in terms of the number of “contributing” atoms. This index is close to 1.0 for much localized LWF, and it is > 1.0 for more diffuse LWFs. The polarization fraction, (9.49) for all LWFs is also given.

Figure 9.3 presents the fragment of crystal containing four primitive unit cells to show the axes orientation: the oxygen atom is positioned in the center and the two nearest Ti or Zr atoms lie on the *z*-axis.

Fig. 9.3 Local environment of oxygen atom in cubic perovskites SrMO_3 ($M = \text{Ti, Zr}$)

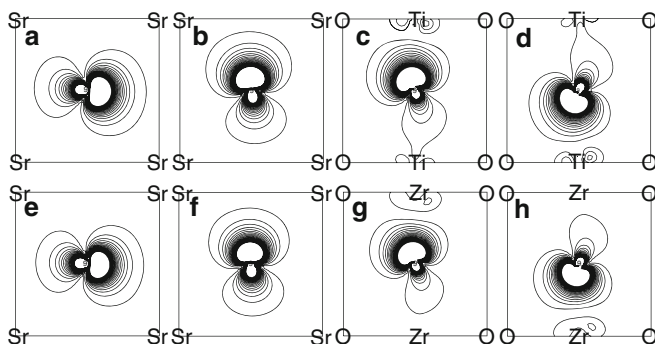
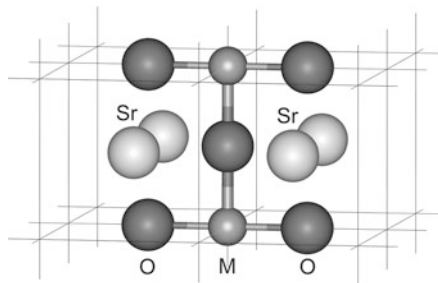


Fig. 9.4 Localized orbitals for oxygen atom in cubic SrTiO_3 (a,b,c,d) and SrZrO_3 (e,f,g,h). Functions a,b,e,f in Sr-plane; functions c,d,g,h in M–O plane ($M = \text{Ti, Zr}$)

The counter density maps of the obtained LWFs are shown in Fig. 9.4.

As is well seen from Fig. 9.4 and Table 9.21 (functions a, b and e, f) two of the four LWFs for each crystal are perpendicularly oriented toward the M–O–M line and lie along x - (Fig. 9.4, a and e) and y - (Fig. 9.4, b and f) axes, respectively.

The polarization fractions of LWFs a, b for SrTiO_3 and e, f for SrZrO_3 are very close to 1.0; *that is*, these LWFs practically represent the electron lone pairs of oxygen ions O^{2-} with a predominant contribution of oxygen $2p_x$ - and $2p_y$ -orbitals. Two other LWFs (see Fig. 9.4 c, d, g and h) are directed along the z -axis. As can be seen from the populations (Table 9.21), they closely correspond to hybrid sp_z orbitals of oxygens. The polarization fractions are substantially less than 1.0 for these two orbitals, revealing the rather strong covalent character of Ti (Zr)–O bonds in both crystals (these covalency effects are well known for transition-metal–oxygen compounds). Thus, localized Wannier functions, generated with the inclusion of only the valence-band states, appear to be a useful tool in analyzing the electronic distribution and chemical bonds in solids. It should be noted that the LWFs obtained are not entirely symmetry-agreed: they do not transform via the representations of the oxygen atom site-symmetry group under the point-symmetry operations because there is no explicit symmetry constraints in the localization procedure [60]. Further symmetrization of WTAOs is desirable to correlate the results with those qualitatively known in quantum chemistry. This symmetrization

procedure was discussed in Sect. 9.1.6 and allows the LWFs centered on oxygen atoms and transforming over e_u and a_{1u} irreducible representations of the oxygen site-symmetry group D_{4h} to be obtained. The symmetrization of LWF is considered in general form in [103].

Concluding this section we note that the projection technique with PW calculations gives reasonable results for local properties of electronic structure, close to those obtained in LCAO calculations after using WTAO population analysis. In general, WTAO results correspond to the more ionic bonding. The useful information about the atomic nature of the band states is obtained in the PW calculations of solids from the orbital and site decompositions of the densities of states (DOS). As an example, we refer to the DFT PW calculations [604] of transparent conductive oxides $\text{In}_4\text{Sn}_3\text{O}_{12}$ and $\text{In}_5\text{SnSbO}_{12}$ —complicated rhombohedral structures with 19 atoms in the primitive unit cell. It was found by DOS analysis that the tops of the valence states of both materials are formed by oxygen $2p$ states, whereas the bottom of the conduction bands are due primarily to the Sn $5s$ electrons. For such crystals LCAO calculations with a posteriori WTAO generation or the projection technique application would be very cumbersome.

The analysis of DOS and other one-electron properties of crystals in the LCAO calculations is discussed in the next section.

9.2 Electron Properties of Crystals in LCAO Methods

9.2.1 One-Electron Properties: Band Structure, Density of States, and Electron Momentum Density

The local properties of chemical bonding in crystals considered above are defined by the electron-density distribution in real space described by a one-electron-density matrix (DM), see (4.125)–(4.127). The latter is calculated self-consistently for the finite set of L discrete $\mathbf{k}$ -points in BZ and corresponds to the cyclic cluster of L -primitive unit cells modeling the infinite crystal:

$$\rho_{\mu\nu}(\mathbf{R}_n) = \frac{1}{L} \sum_{i=1}^M \sum_{j=1}^L \exp(-i\mathbf{k} \cdot \mathbf{R}_n) C_{i\mu}(\mathbf{k}_j) C_{i\nu}^*(\mathbf{k}_j) n_i(\mathbf{k}_j) \quad (9.64)$$

The total number of bands M in (9.64) equals the number of AOs associated with the primitive unit cell. The one-electron energy levels form energy bands consisting of L levels in each band. Therefore, each energy band can allocate $2 \times L$ electrons; if in the unit cell there are n electrons, and the bands do not cross, the lowest $n/2$ bands are occupied and are separated from the empty bands. In this case the occupation numbers in (9.64) are $n_i = 2, 0$ for the occupied and empty bands, respectively (insulators and semiconductors). However, if n is odd, or if the valence and conduction bands cross, more than $n/2$ bands are partially occupied (metal).

The eigenvalue spectrum of an infinite periodic system does not consist of discrete energy levels as the wavevector $\mathbf{k}$ changes continuously along the chosen direction of the BZ. The DM of an infinite crystal is written in the form where the summation over the discrete $\mathbf{k}$ -vectors of the BZ is replaced by the integration over the BZ. In the LCAO approximation written for the cyclic cluster (4.126) for DM in the coordinate space is replaced by

$$\begin{aligned}\rho_{\mu\nu}(\mathbf{R}_n) &= \sum_{i=1}^M \rho_{\mu\nu}^{(i)}(\mathbf{R}_n) \\ &= \frac{1}{V_{BZ}} \sum_{i=1}^M \int_{BZ} \exp(-i\mathbf{k} \cdot \mathbf{R}_n) C_{i\mu}(\mathbf{k}) C_{i\nu}^*(\mathbf{k}) (\varepsilon_F - \varepsilon_i(\mathbf{k})) d\mathbf{k} \quad (9.65)\end{aligned}$$

where $\rho_{\mu\nu}^{(i)}(\mathbf{R}_n)$ is the contribution of the i th energy band.

For the infinite crystal at each cycle of the SCF process, an energy ε_F (the Fermi energy) must be determined, such that the number of one-electron levels with energy below ε_F is equal to the number of electrons (or, in other words, the number of filled bands below ε_F is equal to half the number of electrons in the unit cell). The Fermi surface is the surface in reciprocal space that satisfies the condition $\varepsilon_i(\mathbf{k}) = \varepsilon_F$. By limiting the integration over the BZ to states with energy below ε_F , a Heaviside step function $\theta(\varepsilon_F - \varepsilon)$ excludes the empty states from the summation over the energy bands. In fact, the band structure of the infinite crystal is obtained after the cyclic-cluster self-consistent calculation by the interpolation of the one-electron energy levels considered as continuous functions $\varepsilon(\mathbf{k})$ of the wavevector. The band structure of solids is an important feature, defining their optical, electrostatic and thermal properties. Both the electron charge distribution and the band structure are defined by the self-consistent DM of a crystal.

As we have seen, two binary oxides—MgO in sodium chloride structure and TiO₂ in rutile structure (see Chap. 2 for descriptions of these structures)—differ significantly in the character of chemical bonding, which is due to the electron-density distribution being much different in them. We discuss now the differences in the band structures of these crystals.

The electronic structures of both compounds have been well studied experimentally. The experimental data show that the MgO crystal is a wide-bandgap insulator ($E_g = 7.8$ eV); titanium dioxide TiO₂ in the rutile structure is a semiconductor with an experimental bandgap of approximately 3 eV. These differences are reproduced in the band structure of these two binary oxides, calculated in [607] by HF and LDA LCAO methods and shown in Figs. 9.5 and 9.6, respectively. The details of the AO basis-set choice and BZ summation can be found in [607].

In MgO (in accordance with the results of other calculations), the two highest valence bands are the oxygen s - and p -like bands, respectively, whereas the conduction bands are more complicated. The upper valence bands in TiO₂ are also oxygen s - and p -like bands; however, they consist of 4 and 12 sheets, respectively, because the primitive cell of titanium oxide contains four oxygen atoms.

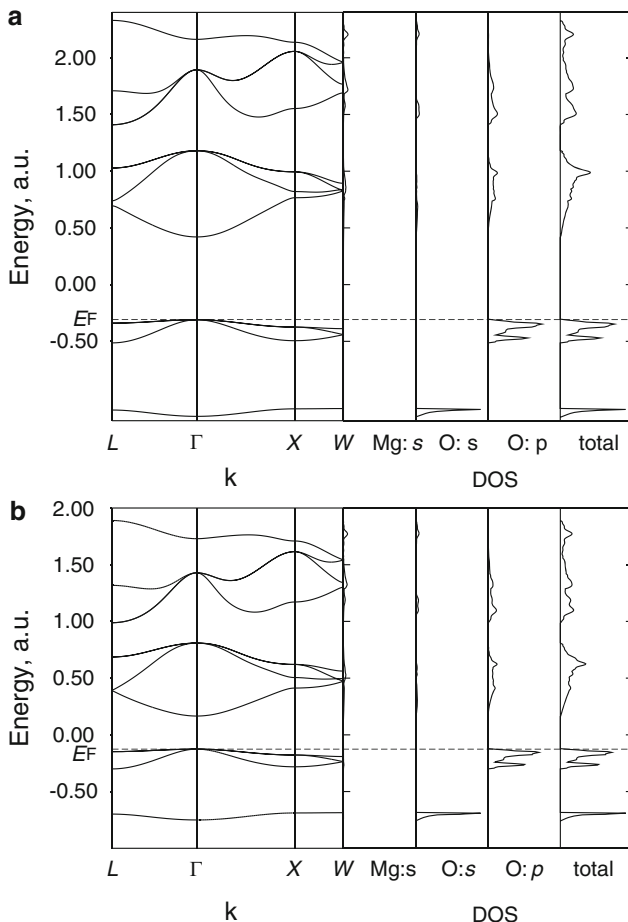


Fig. 9.5 Band structure and DOS of MgO crystal, [607]: (a) HF LCAO method; (b) DFT(LDA) LCAO method

The lowest conduction band in TiO_2 consists of 10 branches formed by $3d$ -states of two titanium atoms and is noticeably separated in energy from the upper conduction bands. The symmetry of the one-electron states can be found using the BR theory of space groups and data on the crystalline structures (see Chap. 3).

Evidently the symmetry of band states does not depend on the basis choice for the calculation (LCAO or PW); the change of basis set can only make changes in the relative positions of one-electron energy levels.

An important parameter in the band theory of solids is the Fermi-level energy (see Figs. 9.5 and 9.6), the top of the available electron energy levels at low temperatures. The position of the Fermi level in relation to the conduction band is a crucial factor in determining electrical and thermal properties of solids. The Fermi energy is the

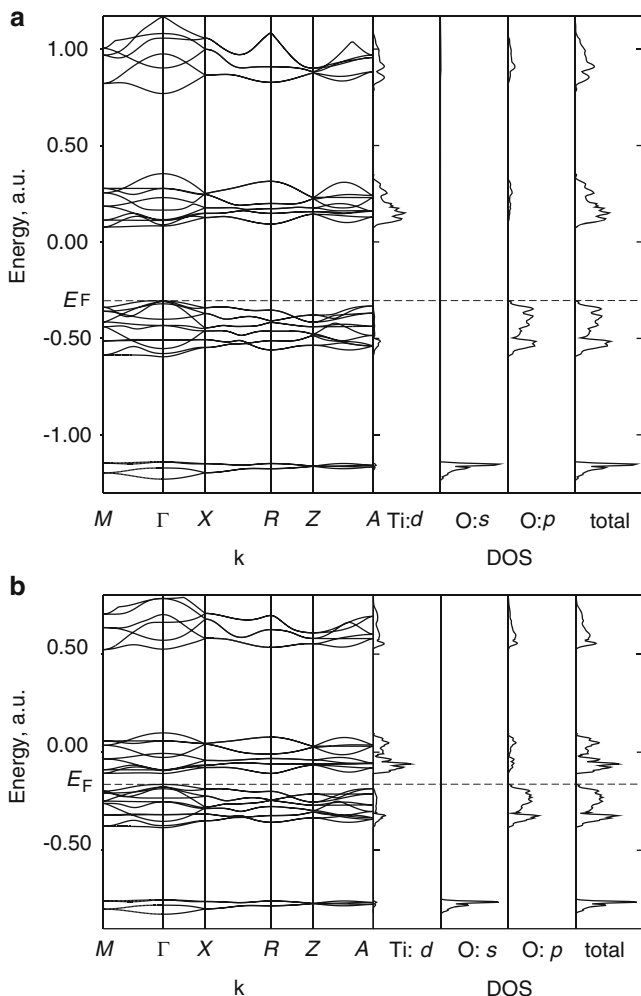


Fig. 9.6 Band structure and DOS of rutile TiO_2 crystal, [607]: (a) HF LCAO method; (b) DFT(LDA) LCAO method

analog of the highest-occupied MO energy (HOMO) in molecules. The LUMO (the lowest-unoccupied MO) energy in molecules corresponds to the conduction-band bottom in solids. The HOMO–LUMO energy interval in a solid is called the forbidden energy gap or simply bandgap.

Depending on the translation symmetry of the corresponding Bloch states the gap may be direct or indirect. In HF and LDA calculations of both crystals under consideration the bandgap is direct, *that is*, the one-electron energies at the top of the valence band and the bottom of the conduction band belong to the same Γ -point of the BZ (this result agrees both with the experiment and other band-structure

calculations). It is seen that the HF bandgap in both crystals is essentially overestimated and decreases in LDA calculations mainly due to the lowering of the conduction-band bottom energy (see Chap. 7). The influence of the correlation effects on the valence-band states is smaller.

It is also seen that the oxygen $2p$ bandwidth in MgO is smaller than that in TiO_2 . The bandwidth is a measure of dispersion in the $\mathbf{k}$ -space and depends on the magnitude and the range of interactions within the crystal: for the more covalent rutile crystal the oxygen–oxygen interactions are stronger. The core bands of both crystals (not shown on the figures) are separated by a large energy gap from the valence bands and are completely flat due to the high localization of core states near the atomic nuclei.

The Fermi energy of a crystal with n electrons in the primitive unit cell is defined from the condition

$$n = 2 \sum_{i=1}^M \int_{-\infty}^{\varepsilon_F} \frac{1}{V_B} \int_{BZ} \theta(\varepsilon - \varepsilon_i(\mathbf{k})) d\mathbf{k} = \int_{-\infty}^{\varepsilon_F} n(\varepsilon) d\varepsilon = \sum_i \int_{-\infty}^{\varepsilon_F} n_i(\varepsilon) d\varepsilon \quad (9.66)$$

where $n(\varepsilon)$ is the total density of states (DOS) per unit energy. DOS is an important quantity calculated for crystals. The total DOS can be expressed as the sum of contributions $n_i(\varepsilon)$ from individual energy bands, see (9.66). The total DOS definition is independent of the basis-set choice (PW or LCAO); the product $n_i(\varepsilon)d\varepsilon$ defines the number of states with energy in the interval $d\varepsilon$. Each energy band spans a limited energy interval between the minimal and maximal one-electron energies $\varepsilon_{\min}$, $\varepsilon_{\max}$ so that $\int_{\varepsilon_{\min}}^{\varepsilon_{\max}} n(\varepsilon) d\varepsilon$ gives DOS in the corresponding energy interval.

The connection between the electronic structure of a crystal and the one-electron states of the constituent atoms is given by the projected density of states (PDOS), associated with the separate AOs, their shells or individual atoms.

Let us rewrite the total DOS as

$$n(\varepsilon) = \sum_{i=1}^M n_i(\varepsilon) = \frac{1}{V_B} \sum_{i=1}^M \int_{BZ} f^i(\mathbf{k}) \delta(\varepsilon - \varepsilon_i(\mathbf{k})) d\mathbf{k} \quad (9.67)$$

The weighting function $f^{(i)}(\mathbf{k})$ in (9.67) chosen as

$$f^{(i)}(\mathbf{k}) = C_{i\mu}(\mathbf{k}) C_{i\nu}^*(\mathbf{k}) \exp(-i\mathbf{k}\mathbf{R}_n) \quad (9.68)$$

defines PDOS associated with AO μ in the reference cell and AO ν in the cell with the translation vector $\mathbf{R}_n$. After summation over band index i and integration up to ε_F PDOS (9.68) gives the density-matrix elements (9.65).

According to Mulliken population analysis, the DOS projected onto a given set of AOs $\{\lambda\}$ (belonging to the given shell or to the whole atom), is defined by the weight function

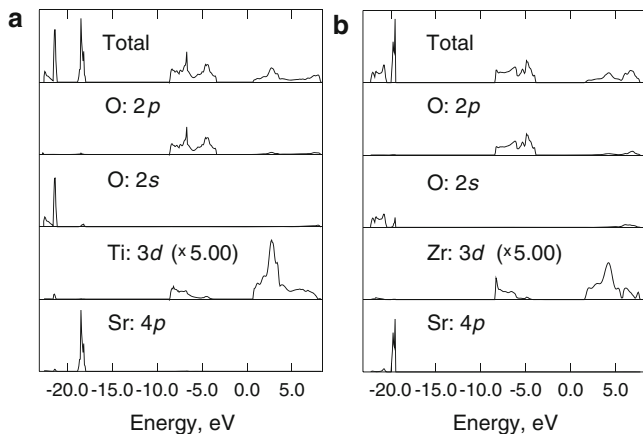


Fig. 9.7 Full and partial DOS in (a) SrTiO_3 and (b) SrZrO_3 crystals

$$f_{\{\lambda\}}^{(i)}(\mathbf{k}) = \sum_{\mu \in \{\lambda\}} \sum_v C_{i\mu}(\mathbf{k}) C_{iv}^*(\mathbf{k}) S_{\mu v}(\mathbf{k}) \quad (9.69)$$

where the overlap integral $S_{\mu v}(\mathbf{k})$ is defined by (4.123).

Let the set $\{\lambda\}$ consist of one AO from the reference cell. The summation of (9.69) over the direct lattice translations $\mathbf{R}_n$ and integration over BZ gives the orbital DOS

$$n_{\mu}(\varepsilon) = \frac{1}{V_{\text{BZ}}} \sum_i \sum_v \sum_{\mathbf{R}_n} \int_{\text{BZ}} C_{i\mu}(\mathbf{k}) C_{iv}^*(\mathbf{k}) \exp(i\mathbf{k} \cdot \mathbf{R}_n) S_{\mu v}(\mathbf{k}) \delta(\varepsilon - \varepsilon_i(\mathbf{k})) d\mathbf{k} \quad (9.70)$$

The DOS of an atom A $n_A(\varepsilon)$ and the total DOS $n_{\text{tot}}(\varepsilon)$ are calculated from the orbital DOS:

$$n_A(\varepsilon) = \sum_{\mu \in A} n_{\mu}(\varepsilon); n_{\text{tot}}(\varepsilon) = \sum_A n_A(\varepsilon) \quad (9.71)$$

The total DOS and PDOS give rich information on the chemical structure of a system, connecting the calculated band structure with the atomic states. We demonstrate this by considering total and projected DOS for binary oxides MgO , TiO_2 and ternary oxides SrTiO_3 and SrZrO_3 with cubic perovskite structure (see Figs. 9.5–9.8).

The analysis of total and partial DOS demonstrates that in all the oxides under consideration the upper valence band is predominantly formed by the O 2p states. It can also be seen that Mg 3s, Ti 3d and Zr 4d states make the dominant contribution to the bottom of the conduction band.

As is seen from Fig. 9.8, the inclusion of correlation effects moves the valence and conduction bands to the higher and lower energies, respectively, which

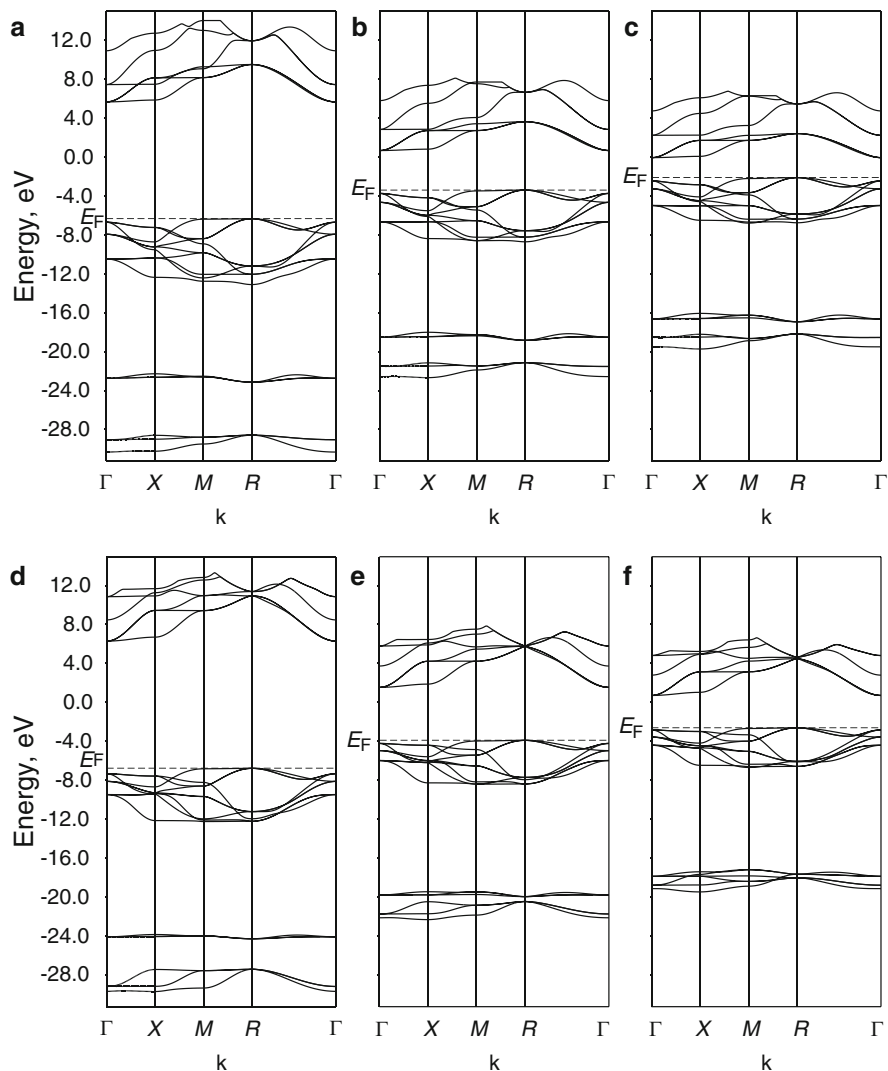


Fig. 9.8 Band structure of cubic crystals: (a),(b),(c)—SrTiO₃, (d),(e),(f)—SrZrO₃. HF LCAO method—(a),(d); hybrid HF-DFT(PBE0) LCAO method—(b),(e); DFT(PBE) LCAO method—(c),(f)

decreases the bandgap. In more ionic strontium zirconate the energy bands are narrower than in less ionic strontium titanate.

The ground-state electron charge density in a crystal can be expressed as

$$\rho(\mathbf{r}) = \sum_{\mu\nu} \sum_{\mathbf{R}_n} \sum_{\mathbf{R}_m} \rho_{\mu\nu}(\mathbf{R}_n - \mathbf{R}_m) \chi_{\mu}(\mathbf{r} - \mathbf{R}_n) \chi_{\nu}(\mathbf{r} - \mathbf{R}_m) \quad (9.72)$$

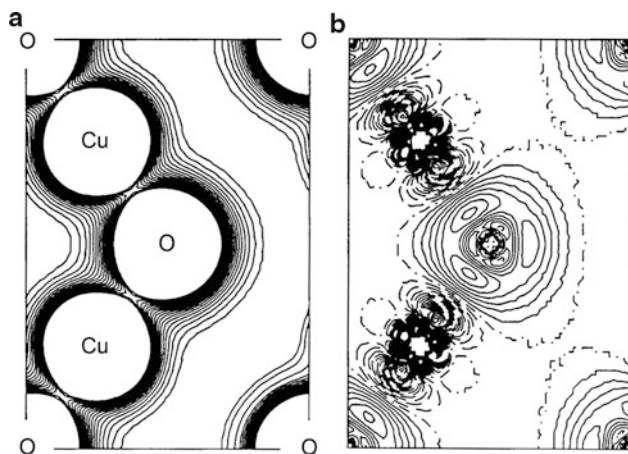


Fig. 9.9 Electron-density maps obtained for Cu₂O on a (110) plane, [606]. (a) Total electron density. (b) Density difference maps, bulk minus neutral atom superposition. Values corresponding to neighboring isodensity lines differ by 0.01 e/Bohr³. The full and broken curves in (b) indicate density increase and decrease, respectively

and reproduces the essential features of the electron-density distribution near atomic nuclei and along interatomic bonds. For each $\mathbf{r}$ the sums over $\mathbf{R}_n$ and $\mathbf{R}_m$ are restricted to those direct lattice vectors such that the value of $\chi_\mu(\mathbf{r} - \mathbf{R}_n)$ and $\chi_\nu(\mathbf{r} - \mathbf{R}_m)$ are nonnegligible.

The total electron-density maps provide a pictorial representation of the total electronic distribution and are obtained by calculation of the charge density in a grid of points belonging to some planes. More useful information is obtained by considering difference maps, given as a difference between the crystal electron-density and a “reference” electron density. The latter is a superposition of atomic or ionic charge distributions.

Figure 9.9 shows the total and difference maps for Cu₂O crystal, obtained in HF LCAO calculations [606].

Two important quantities that require an integration involving $\rho(\mathbf{r})$ are the electrostatic potential and the electric field, [314]. In particular, maps of the electrostatic potential created by electrons and nuclei at a crystal surface may be useful for gathering information about reaction paths and active sites of electrophilic or nucleophilic chemical processes at the surface. As concerns the electric field, it may be of interest to calculate the electric field gradient at the location of nuclei with a nonzero nuclear quadrupole moment, since comparison with experimental data is possible in such cases.

Three functions may be computed that have the same information content but different use in the discussion of theoretical and experimental results [21]: the electron momentum density itself (EMD) $\rho(\mathbf{p})$; the Compton profile (CP) function $J(\mathbf{p})$; the autocorrelation function, or reciprocal-space form factor, $B(\mathbf{r})$.

Let $\chi_\mu(\mathbf{p})$ be defined as the Fourier transform of AO $\chi_\mu(\mathbf{r})$ belonging to atom A

$$\chi_\mu(\mathbf{p}) = \int \exp(i\mathbf{p}\mathbf{r})\chi_\mu(\mathbf{r})d\mathbf{r} \quad (9.73)$$

and s_μ is the fractional coordinate of atom A in the reference cell.

EMD is defined as the diagonal element of the six-dimensional Fourier transform of the one-electron-density matrix from coordinate to momentum space:

$$\rho(\mathbf{p}) = \sum_{\mu\nu} \sum_{\mathbf{R}_n} \rho_{\mu\nu}(\mathbf{R}_n) \exp(-i\mathbf{p}(\mathbf{R}_n + \mathbf{s}_\mu - \mathbf{s}_\nu)) \chi_\mu(\mathbf{p}) \chi_\nu(\mathbf{p}) \quad (9.74)$$

The Compton profile function is obtained by 2D integration of the EMD over a plane through and perpendicular to the direction

$$J(\mathbf{p}) = \int \rho(\mathbf{p} + \mathbf{p}'_\perp) d\mathbf{p}'_\perp \quad (9.75)$$

after indicating with $\mathbf{p}'_\perp$ the general vector perpendicular to $\mathbf{p}$.

It is customary to make reference to CPs as functions of a single variable p , with reference to a particular direction $\langle hkl \rangle$ identified by a vector $\mathbf{e} = (h\mathbf{a}_1 + k\mathbf{a}_2 + l\mathbf{a}_3)/|h\mathbf{a}_1 + k\mathbf{a}_2 + l\mathbf{a}_3|$. We have

$$J_{\langle hkl \rangle}(p) = J(\mathbf{p}\mathbf{e}) \quad (9.76)$$

The function $J_{\langle hkl \rangle}(p)$ is referred to as directional CPs. The weighted average of the directional CPs over all directions is the average CP. In the so-called impulse approximation, $J_{\langle hkl \rangle}(p)$ may be related to the experimental CPs, after correction for the effect of limited resolution [21].

Once the directional CPs are available, the numerical evaluation of the corresponding autocorrelation function, or reciprocal-space form factor, $B(\mathbf{r})$ is given by the 1D Fourier transform:

$$B_{\langle hkl \rangle}(\mathbf{r}) = \frac{1}{\pi} \int_{-\infty}^{\infty} J_{\langle hkl \rangle}(p) \exp(i\mathbf{p}\mathbf{r}) d\mathbf{p} \quad (9.77)$$

The structural and electronic properties of Cu_2O have been studied in [606] using the HF LCAO method and a posteriori density-functional corrections. The electronic structure and bonding in Cu_2O were analyzed and compared with x-ray photoelectron spectroscopy spectra, showing a good agreement for the valence-band states. The Fourier transform of the ground-state charge density of a crystalline system provides the x-ray structure factors of the crystal, which can be determined experimentally by x-ray diffraction. To check the quality of the calculated electron density in Cu_2O crystal, structure factors have been calculated in [606], showing a good agreement with the available experimental data, see Table 9.22.

Table 9.22 Structure factors for Cu_2O calculated with the periodic HF LCAO method, [606]. Experimental values are obtained from x-ray data

hkl	F_{calc}	F_{expt}
110	13.52	12.42
111	94.78	93.70
200	79.48	78.98
211	9.10	8.53
220	84.34	82.52
222	61.07	59.40
310	6.94	6.56
311	69.22	67.49
330	4.63	4.71
331	55.57	53.78
332	4.39	4.24
333	46.86	45.42
400	65.05	63.09
411	4.80	4.71
420	49.72	48.06
422	53.90	52.18

9.2.2 Magnetic Structure of Metal Oxides in LCAO Methods: Magnetic Phases of LaMnO_3 and ScMnO_3 Crystals

The crystalline transition-metal oxides TiO_2 , SrTiO_3 , SrZrO_3 considered above are classified as d^0 insulators with quite wide bandgap, being diamagnetic with no unpaired electrons. This means that these crystals have no inherent magnetization, but when subjected to an external field develop magnetization that is opposite to the field (the transition atom spins tend to be oriented in the direction opposite to the field). As we saw in the preceding subsection, the bandgap in d^0 insulators is between a filled band of bonding orbitals, with predominately oxygen $2p$ atomic character, and an empty metal d band of antibonding orbitals.

The transition-metal oxides with d^n ions (such as NiO , Cr_2O_3 , LaMnO_3) form a class of compounds with the localized “impurity-like” d -levels [608]. These systems are known as Mott–Hubbard or magnetic insulators (exhibit magnetic order in the absence of an external field); their magnetic properties indicate the unpaired electrons expected for the appropriate d^n open-shell configuration. $d-d$ transitions in these crystals appear due to the crystal-field splitting and give rise to optical absorptions, with only quite weak perturbations from those expected for isolated d^n ions. These oxides have narrow upper valence bands (1–2 eV), because of small overlap between the metal d and oxygen $2p$ orbitals, so that their local electronic structure can be described in terms of atomic-like states. The fully ionic O^{2-} configuration is not exactly the state of an oxygen atom in a crystal, and O^- mobile and correlated configuration (oxygen holes with $2p^5$ configuration) has to be included. The weak interactions between magnetic moments of d^n -ions give rise to magnetic ordering (most commonly antiferromagnetic at low temperatures). At the same time, these compounds are good insulators with bandgaps that may be as large

as those in some d^0 compounds. Like the latter, however, the magnetic insulators are susceptible to nonstoichiometry, and this may give rise to semiconductive properties and strong optical absorptions. For example, NiO is green and highly insulating when pure, but easily takes up excess oxygen to become black and semiconducting.

The magnetic insulators have an extraordinary range of structures and properties [609] and provide an excellent case study in quantum chemistry of solids. The existence of a magnetic ground state is a many-body effect caused by correlated electron–electron interactions. The need for the inclusion of electron correlation effects has limited the majority of applications to solids by DFT methods. We noted in Chap. 7 that due to the strong Coulomb correlations DFT methods are in serious trouble for systems with localized electrons as these methods overestimate delocalization of the electron density due to nonexact cancelation of the electron self-interaction. DFT results in many cases are in disagreement with experiment. For example, when the LDA is used to describe the magnetically ordered insulating ground states of NiO, a nonmagnetic metallic state is obtained [610]. Initially, this was thought to be a failure of the one-electron approximation itself, meaning that such highly correlated systems could not be described using band theory. It is now apparent that this is not case [611]: the failure of DFT was due to its approximate treatment of the exchange interaction. Analyzing different approaches, introducing better descriptions of the onsite exchange interactions we concluded in Chap. 7 that LCAO calculations with hybrid DFT functionals can play the same role in quantum chemistry of solids as DFT+U and SIC DFT calculations (with PW and LMTO basis) in solid-state physics. This is demonstrated by the results of recent numerous LCAO (UHF and hybrid DFT) calculations of the properties of magnetic insulators [552].

The magnetic properties of different oxides have been investigated in the LCAO approximation: MO (M=Ni, Mn), [612], M_2O_3 (M=Cr, Fe), [613, 614], Mn_3O_4 , [615], $CuGeO_3$, $Ag_2Cu_2O_3$, [616], high- T_c superconductor parent compounds $A_2CuO_2X_2$ (A=Ca, Sr, X=F, Cl), [617]. The main parameter used to quantify the magnetic properties is the exchange coupling constant between the paramagnetic centers with total spins S_i and S_j that is defined through the phenomenological Heisenberg–Ising Hamiltonian with total spin operators $\hat{S}$:

$$\hat{H} = - \sum_{i>j} J'_{ij} \hat{S}_i \hat{S}_j = - \sum_{i \neq j} J_{ij} \hat{S}_i \hat{S}_j \quad (9.78)$$

The interactions are generally assumed to be limited to nearest neighbors, but the range of interactions can be extended beyond the nearest neighbors (we refer the reader to Chap. 7 in [9] for a detailed discussion of magnetic behavior of solids and the Heisenberg–Ising model). The comparison of calculated exchange coupling constants with those obtained experimentally is, however, not straightforward since experimental data are in most cases obtained from a fitting of the magnetic susceptibility to the expression obtained using a model that includes simplifying assumptions [616]. The latter are adopted to reduce the number of fitting parameters.

In this situation the use of theoretical methods to estimate the exchange coupling constants becomes a valuable tool for the experimentalists.

We discuss here in more detail the recent applications of LCAO methods to the LaMnO_3 and ScMnO_3 crystals, two representatives of the rare-earth manganese oxides, RMnO_3 ($R = \text{La, Sc}$). The structures of these two crystals were described in Chap. 2. LaMnO_3 crystal has the orthorhombic perovskite structure, found in RMnO_3 with a large ionic radius of rare-earth element R ($R = \text{La, Pr, Nd, Sm, Eu, Gd, and Tb}$). ScMnO_3 crystal has hexagonal structure found in RMnO_3 oxides containing the rare-earth elements with a small ionic radius ($R = \text{Ho, Er, Tm, Yb, Lu, and Y}$). We note that some of the hexagonal manganites can also form in the orthorhombic structure depending on the heat treatment.

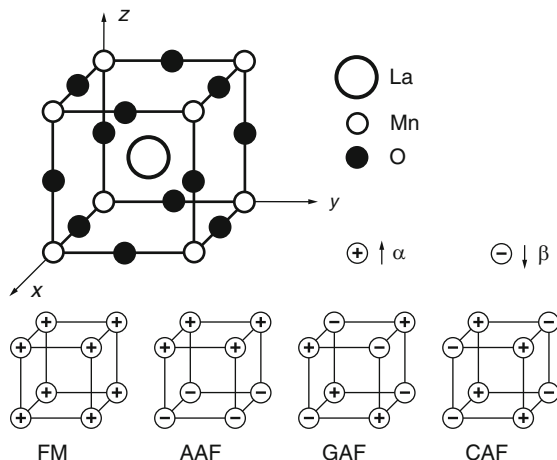
Perovskite materials display a wide variety of fundamental properties, from magnetism to ferroelectricity, from colossal magnetoresistance to half-metallicity; they are used in a number of important technological applications, such as transducers and memories. They also show electronic and structural peculiarities including orbital and charge ordering, formation of local moments, and Jahn–Teller distortions. Such a richness of properties, combined with their relatively simple structure, makes them ideal materials for investigating the general principles that govern these properties. Unlike the recently extensively studied perovskite manganites, the hexagonal RMnO_3 compounds have a ferroelectric transition at very high temperature (*e.g.*, 900 K for YMnO_3), and an antiferromagnetic transition at a much lower temperature (*e.g.*, 570 K for $\text{YMnO}_{3.7}$). Such compounds are known as ferroelectromagnets.

There exists a series of LaMnO_3 bulk electronic-structure calculations, using a number of first-principles methods, *for example*, UHF LCAO [618, 619], LDA+U PW [620], and relativistic FPGGA LAPW [621]. LCAO studies with hybrid DFT functionals [622, 623] provided a most reliable description of the electronic and magnetic structure of LaMnO_3 . These studies deal with the energetics of the ferromagnetic (FM) and antiferromagnetic (AF) phases. The experiments show that below 750 K the cubic perovskite phase of LaMnO_3 with a lattice constant of $a_0 = 3.95 \text{ \AA}$ is transformed into the orthorhombic phase (four formula units per unit cell). Below $T_N = 140 \text{ K}$ (Neel temperature) the A-type AF configuration (AAF) is the lowest in energy. This corresponds to the ferromagnetic-coupling in the basal ab (xy) plane combined with antiferromagnetic coupling in the c (z)-direction in the $Pbnm$ setting, see Fig. 9.10.

Also, FM, GAF and CAF magnetic states exist: FM corresponds to a fully ferromagnetic material, in GAF all the spins are antiferromagnetically coupled to their nearest neighbors, and in a CAF cell the spins are antiferromagnetically coupled in the basal plane and ferromagnetically between the planes (along the c -axis). In the DFT LCAO calculations [623] Becke three-parameter hybrid functional (B3PW) was applied, [361], which uses in the exchange part the mixture of the Fock (20%) and Becke's (80%) exchange, whereas in the correlation part the Perdew–Wang (PWGGA) nonlocal correlation functional is employed. As was demonstrated in [590], the B3PW functional gives the best description of the atomic and electronic structures, as well as elastic properties of several ABO_3 perovskite

Fig. 9.10 Magnetic ordering in LaMnO_3 crystal.

FM—ferromagnetic ordering,
AAF, GAF, CAF—
antiferromagnetic orderings



materials. In some cases, for a comparison the B3LYP hybrid functional was also used (the exchange part is the same as in the B3PW functional and the correlation is the Lee–Yang–Parr nonlocal functional). For comparison, the DFT PW calculations with the PW91 GGA nonlocal functional were made in [623]. As was noted earlier DFT PW calculations with hybrid functionals are not implemented in modern computer codes.

The relative smallness of the total energy differences between different magnetic phases requires a high numerical accuracy in the direct lattice and Brillouin-zone summations. Therefore, in [623] the cutoff threshold parameters of the CRYSTAL code for Coulomb and exchange integrals evaluation have been set to 7, 7, 7, 7, and 14, respectively. The integration BZ has been carried out on the Monkhorst–Pack grid of shrinking factor 8 (its increase up to 16 gave only a small change in the total energy per unit cell).

The self-consistent procedure was considered as converged when the total energy in the two successive steps differs by less than 10^{-6} a.u. In order to check how the results depend on the basis-set (BS) choice, B3LYP and B3PW LCAO calculations were performed for the cubic LaMnO_3 with one formula unit per primitive cell with the experimental lattice constant of 3.95 Å. Five different BS (BS1–BS5) were used, including the BS optimized both in all-electron (AE) and pseudopotential calculations (large- and small-core Hay–Wadt pseudopotentials were taken for La and Mn atoms). The details of BS optimization and choice are given in [623]. The total energies for the cubic structure (with the five atom primitive unit cell) obtained in nonspin-polarized and spin-polarized B3PW calculations were compared with different magnetic ordering of four d electrons on the Mn^{3+} ion (the d -levels are split in the cubic field into t_{2g} and e_g levels, the latter are higher in energy than the former): total spin projection $S_z = 2$ (four electrons occupy t_{2g} and e_g levels), $S_z = 1$ (three α electrons and one β electron occupy the t_{2g} level), and $S_z = 0$ (two α electrons and two β electrons occupy the t_{2g} level). The calculated

self-consistent Mn atom magnetic moment is close to 0, 2 and 4 for the three cases under consideration. Since the number of electrons per cell depends on the basis used (AE or without core electrons), the absolute values of these energies are quite different. The basis optimization for the same BS choice results in a lower energy for the same spin projection. It was shown that the order of relative energies for different magnetic configurations is the same for all BS chosen and even the absolute values of energy differences are close. Independently of the BS choice the lowest total energy per cell corresponds to the maximal spin projection $S_z = 2$, *that is*, for the Mn^{3+} ion in a crystal the Hund rule holds and the lowest energy corresponds to the maximal spin. This result demonstrates that the magnetic behavior of insulators can usually be discussed in terms of the physics that applies to isolated atoms or ions that have a magnetic moment. The Mulliken atomic charges remain practically the same for different magnetic orderings, provided the BS is fixed. At the same time, their absolute values show the BS dependence for the same spin projection value. The relative energies of different magnetic orderings reveal the same sign in PW DFT and LCAO calculations (the lowest energy corresponds to $S_z = 2$). The Bader atomic charges, calculated in the PW DFT method, compared with the Mulliken charges, are much smaller and also show a weak dependence on the magnetic ordering.

To study the magnetic ordering in LaMnO_3 , the so-called broken symmetry approach was adopted [622]. It allows one to deduce the magnitude of the magnetic coupling data making spin-polarized calculations for different magnetic orderings of transition-metal atoms. LaMnO_3 is stabilized at moderate temperatures in the orthorhombic structure comprising four formula units, space group D_{2h}^{16} (in $Pbnm$ and $Pnma$ settings the largest orthorhombic lattice translation vector is directed along the z or y axis, respectively; in what follows, the $Pbnm$ setting is chosen). The real structure can be viewed as a distorted cubic perovskite structure with a quadrupled tetragonal unit cell ($a_p\sqrt{2}, a_p\sqrt{2}, 2a_p$) where a_p is the lattice parameter of the cubic perovskite structure. This tetragonal cell is slightly distorted in the real orthorhombic structure. The calculations on the tetragonal model (both in LCAO and PW basis), *that is*, four formula units without the structural distortion have shown that LaMnO_3 is metallic in all magnetic states and the ground state is FM. This contradicts the experimental data, for both the energy gap (LaMnO_3 is believed to be a spin-controlled Mott–Hubbard insulator with the lowest-energy $d-d$ transitions around 2 eV [624]) and magnetic AAF ordering in the ground state below 140 K. The results obtained in [623] for cubic LaMnO_3 with the primitive cell of five atoms explain this fact: the tetragonal structure remains in fact cubic, with the tetragonal supercell; since in the primitive unit cell the FM configuration corresponds to the metallic ground state, the same is true for the undistorted tetragonal structure. However, when the orthorhombic atomic distortions are taken into account, the AAF structure turns out to be the ground state, in agreement with experiment.

This is seen from results given in Table 9.23, [623], where the relative energies of different magnetic phases are presented (the energy for the FM phase is taken as zero energy). The calculations were made for orthorhombic structure with the

Table 9.23 The energy (in meV per unit cell) of the different magnetic phases for orthorhombic LaMnO_3 for the experimental structure [625]. The energy of the FM configuration is taken as zero energy. Magnetic moments μ on the Mn atom in μ_B , magnetic coupling constants J_{ab} and J_c in meV. Experimental data: $\mu = 3.87$ for AAF [616], $J_c = -1.2$, $J_{ab} = 1.6$ [624]

Method/basis set	AAF		GAF		CAF		J_c	J_{ab}
UHF(BS1) ^a	-4.8	—	55.6	—	—	—	-0.15	0.94
B3LYP(BS1) ^b	-33.0	3.80	112.0	3.72	120.0	3.73	-0.64	2.07
UHF(BS2) ^c	-8.0	—	48.0	—	56.0	—	-0.25	0.88
B3LYP(BS2) ^b	-33.0	3.78	84.0	3.71	101.0	3.71	-0.78	1.70
UHF(BS3) ^d	-5.2	3.96	51.2	—	55.9	—	-0.15	0.88
Fock-50(BS3) ^d	-12.2	3.89	89.22	—	93.64	—	-0.26	1.52
B3LYP(BS3) ^d	-32.2	3.80	114.0	—	121.5	—	-0.62	2.09
B3LYP(BS4) ^b	-32.0	3.81	103.0	3.73	117.0	3.76	-0.72	1.97
B3LYP(BS5) ^b	-30.0	3.82	106.0	3.74	117.0	3.77	-0.64	1.98
B3PW(BS5) ^b	-19.0	3.86	153.0	3.75	152.0	3.79	-0.28	2.50
GGAPW91(BS5) ^b	-40.0	3.71	248.0	3.58	234.0	3.64	-0.83	4.08
(GGA-PW) ^b	-59.0	3.55	189.0	3.35	224.0	3.46	-1.47	3.69
(LAPW) ^e	-72.0	—	96.0	—	136.0	—	-1.75	2.38
(LMTO) ^f	-62.0	3.46	243.0	3.21	—	—	-1.94	4.76
FLMTO(GGA) ^g	-98.8	—	142.8	—	167.2	—	-1.92	3.19
(LDA+U) ^h	-34.0	—	170.0	—	—	—	-1.06	2.66

^a Reference [619], ^b Reference [623], ^c Reference [618], ^d Reference [622], ^e Reference [626], ^f Reference [627], ^g Reference [628], ^h Reference [629].

structural parameters from a neutron-diffraction study [625]. Magnetic moments μ on the Mn atom and magnetic and coupling constants J_{ab} and J_c are also presented there.

The Ising model Hamiltonian

$$H = -J_{ab} \sum_{ij} S_{zi} S_{zj} - J_c \sum_{kl} S_{zk} S_{zl} \quad (9.79)$$

was used, where J_{ab} and J_c are exchange integrals (magnetic coupling constants) between nearest neighbors in the basal plane (xy) and between nearest neighbors along the c -axis, respectively, S_{zi} stands for the z -component of the total spin on the magnetic center i , and (ij) and (kl) indicate summation over intraplane and interplane nearest magnetic centers, respectively. Due to two different possible choices of the Ising Hamiltonian presentation, we stress that in (9.79) that the form of (9.78) is used that contains double summation over each pair of centers and gives positive values for J_{ab} and negative for J_c . The latter must be taken into account in a comparison with the experimental data obtained by fitting to the Ising Hamiltonian. In particular, experimental J_{ab} and J_c values [625] have to be multiplied by a factor of 2 for the Hamiltonian (9.79).

A set of equations relating the energy differences for the FM, AAF, GAF and CAF configurations with the magnetic coupling constants sought for was used:

$$E(\text{FM}) - E(\text{AAF}) = E(\text{CAF}) - E(\text{GAF}) = -32J_c \quad (9.80)$$

$$E(\text{FM}) - E(\text{CAF}) = E(\text{AAF}) - E(\text{GAF}) = -64J_{ab} \quad (9.81)$$

Again, to avoid misunderstanding, (9.80) and (9.81) are written for a quadruple cell, corresponding to four formula units. For calculating the coupling constants both (9.80) and (9.81) were used and an averaging was performed. Unfortunately, $E(\text{CAF})$ is not always presented in the published results (see Table 9.23). The calculated magnetic coupling constants are compared with the experimental data in the last two columns of Table 9.23. This table demonstrates how the calculated magnetic coupling constants depend on the Hamiltonian choice (LDA, UHF, hybrid) and the BS choice (LCAO, PW, LAPW).

These results can be briefly summarized as follows. Independently from the BS and Hamiltonian used, all calculations mentioned in Table 9.23 correctly reproduce the sign of the experimental exchange integrals and their relative values ($|J_{ab}| > |J_c|$). In all UHF and hybrid (B3LYP, B3PW) calculations the exchange integrals agree better with the experimental data than in DFT calculations. We explain this by the incorporation of the Fock exchange into UHF and the hybrid methods. For example, if we fix the AO basis as BS3 and analyze a series of the UHF (pure Fock exchange), Fock-50 (50% of Fock exchange) and B3LYP (20% of Fock exchange included), the coupling constants J_{ab} and J_c in this series are getting closer to the experimental values. The effect of the correlation part is smaller (compare B3LYP and B3PW results for BS5). The lack of Fock exchange in LCAO GGA and GGA-PW calculations leads to overestimated values of both magnetic coupling constants. This overestimate is well observed also in previous LAPW, FLMT0, and LDA+U calculations. Therefore, in agreement with the conclusions, made by other researchers it is demonstrated that when calculating the experimentally observable magnetic coupling constants, the nonlocal exchange plays an important role. Such hybrid DFT or UHF calculations are practically possible only for the LCAO BS. These results confirm again the conclusion [616] that the CRYSTAL code is a valuable tool for the study of magnetic properties for open-shell transition-metal compounds. The optical gap for the AAF orthorhombic phase was also calculated in [623]. The B3PW LCAO gives 2.9 eV and 4 eV for the Mn d - d and O2 p -Mn d transitions, in good agreement with the experiment [624], whereas the DFT PW gap of 0.6 eV is an underestimate typical for the DFT. These results, in line with those in [622], demonstrate that it is a combination of the nonlocal exchange with correlation effects realized in the hybrid functionals that considerably narrows the gap between calculated and experimental magnetic coupling constants. This questions the generally accepted idea that DFT is better suited than UHF and related methods for the study of transition-metal oxides, in particular, LaMnO₃. The surface calculations of this crystal made in [623] we discuss in Chap. 11.

We noted that the hexagonal manganites RMnO₃ (R = Sc, Y, Ho–Lu) are an interesting group of compounds because of their unusual combination of electric and

magnetic properties. At low temperatures, they show coexistence of ferroelectric and magnetic orderings. ScMnO_3 plays a prominent role in the series of hexagonal manganites. It has the smallest distance between magnetic Mn^{3+} centers along the c -direction and has the highest Neel temperature. Below the temperature 1220 K its structure belongs to space group $P6_3cm$ [630]. The Mn^{3+} ions are surrounded by five oxygen ions that form a distorted trigonal bipyramid, see Fig. 2.18. In this environment the ^5D state of Mn^{3+} with $3d^4$ occupancy splits into three states. The magnetic moment of the Mn^{3+} ions in ScMnO_3 has been measured as $4.11 \mu_B$. Its Neel temperature is 130 K [631], much higher than that of YMnO_3 (71 K), [632]. The assignment of the strong optical absorption band at about 1.6 eV for hexagonal manganites is a matter of debate [633]. From local spin-density approximation (LSDA) and LSDA+U calculations of YMnO_3 [634] this band was interpreted as an interatomic charge-transfer transition from O $2p$ to Mn $3d$ orbitals. In another theoretical study of YMnO_3 based on LSDA and LSDA+U [635], it was found that the states near the top of the valence band have predominantly Mn $3d_{x^2-y^2}$ character, while the lowest-unoccupied subband has Mn $3d_{z^2}$ character. The d -band centers of the occupied and empty bands are separated by 2.0 eV. The latter theoretical result is in agreement with a careful analysis of experimental spectra [633] that revealed that the band at 1.6 eV is due to an intra-atomic $3d - 3d$ transition in the Mn^{3+} ions. The $\text{O}(2p) \rightarrow \text{Mn}(3d)$ charge-transfer transition in LaMnO_3 and related compounds occurs at 3.1 eV or higher. Later experiments on ScMnO_3 [636] were interpreted differently, partly based on previous LSDA calculations. In particular, the strong band in ScMnO_3 (at 1.57 eV), ErMnO_3 (1.59 eV), and YMnO_3 (1.61 eV) was considered now as a charge-transfer band. In this context we have to point out that LSDA values for bandgaps are usually much too small. In [622] a charge-transfer transition in LaMnO_3 was found at 2.3 eV with B3LYP and at 4.0 eV with Fock35 (35 per cents of the HF exchange in the hybrid functional) functionals. Considering that one-particle energies obtained by band-structure calculations do not describe local $d-d$ transitions, the agreement between LSDA charge-transfer and the experimentally determined band may be fortuitous.

The LCAO calculations [637] with the computer code CRYSTAL03, [21] is the first attempt to establish the electronic and magnetic structure of the low-temperature phase of ScMnO_3 from first principles. The solid phase was modeled with three-dimensional periodic supercells of stoichiometry $\text{Sc}_6\text{Mn}_6\text{O}_{18}$. Three different Hamiltonians were used: UHF, hybrid HF–DFT (B3LYP) and DFT (BLYP). In a previous study of magnetic coupling in CuGeO_3 [616] the same Hamiltonians had been compared and it was found that the hybrid HF–DFT B3LYP Hamiltonian gives the most accurate values for the magnetic coupling constant J . Optimized basis functions were used for Mn and O as obtained in [623]. The valence basis of Sc was optimized for Sc_2O_3 bulk crystal, Sc atom inner ($1s$ $2sp$) electrons were described with the Hay–Wadt small-core effective core potential. The $\text{Sc}_6\text{Mn}_6\text{O}_{18}$ cell contains two hexagonal atomic planes. Three magnetic phases were considered: ferromagnetic (FM) when the four unpaired electrons of each of six Mn ions have parallel spins; two antiferromagnetic (AFc and AFa). In the AFc phase the spins of

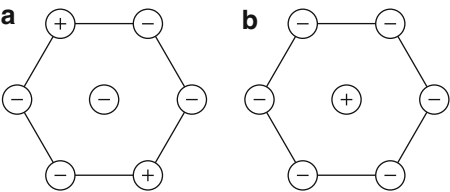


Fig. 9.11 Two local spin configurations in the AFa state in a hexagonal plane; in case (a) the central spin-down Mn ion is surrounded by 4 spin-down and 2 spin-up Mn ions, in (b) the central spin-up Mn ion is surrounded by 6 spin-down Mn ions

Table 9.24 Energy difference (eV) between the AF and the FM states of ScMnO_3 , estimated magnetic coupling constant (meV), Mulliken charges q (a.u.), magnetic moment of Mn ions (μ_B) obtained with three different Hamiltonians [637]

Hamiltonian		J_a	Q_{sc}	Q_{Mn}	Q_{O}	eff
UHF ^a	−0.163	4.1	+2.3	+2.4	−1.5	4.0
B3LYP ^a	−0.555	13.9	+1.9	+2.0	−1.37	3.7
B3LYP ^b	−0.449	11.2	+1.9	+2.0	−1.3	3.8
BLYP ^a	−0.925	23.1	+1.87	+1.9	−1.2	3.5
Exper.		5.5–7.0 ^c				4.11 ^d

^a with fixed structural parameters from experiment [638]
^b with fully optimized in [637] structures
^c estimated from a comparison with YMnO_3 (the Neel temperature 70 K and $J_a = 3.8$ meV)
^d Reference [632]

the Mn ions in different atomic planes along the c -direction are antiparallel, while all spins are parallel in the same plane (between two planes, the Mn–Mn distance is about 5.8 Å, while it is only 3.4 Å in the plane). In the AFa state each plane contains two types of Mn with antiparallel spin in a ratio of 1:2. The local spin arrangements are shown in Fig. 9.11.

This is a simplification of the real situation in ScMnO_3 where the Mn spins are not collinear [631]: the projections of neighboring Mn spins in the same plane are in fact rotated by 120°.

If the FM state and the AFc state are compared, the two neighbors along the c -direction in the planes above and below each magnetic center have different spin. It was found that the corresponding interplane coupling constant $J_c \leq 0.2$ meV for all three Hamiltonians under consideration, *that is*, the magnetic coupling between Mn ions of different planes is negligible. The results of the calculation of intraplane coupling constant are given in Table 9.24. The magnetic coupling constants of ScMnO_3 have not yet been measured at the time of calculations [637]. The simplest assumption is a linear relation between J and the Neel temperature T_N [639]. It is then possible to estimate J_a of ScMnO_3 from the coupling constant of the isostructural compound YMnO_3 (3.0–3.8 meV, [639]). With $T_N = 130$ K for ScMnO_3 and $T_N = 71$ K for YMnO_3 [632] one obtains $J_a = 5.5$ –7.0 meV. In Table 9.24 the calculated coupling constants are compared to this crude estimate.

The UHF method gives $J_a = 4.1$ meV, which is slightly smaller than the estimated value. When electron correlation is taken into account with B3LYP, a much larger value ($J_a = 13.9$ meV) is obtained. But also the description of electron exchange has a substantial effect on the magnetic structure. The BLYP method, which has no contributions from exact HF exchange, gives the largest coupling constant, $J_a = 23.1$ meV. The same ordering of magnetic coupling constants obtained with these methods has been obtained in studies of CuGeO_3 [616], where the B3LYP result favorably agreed with the measured value. Since for ScMnO_3 the deviation from the estimated crude value is substantial with B3LYP, it is likely that the linear extrapolation scheme is inadequate. But before any conclusion was drawn the effect of changes in the local structure on the calculated coupling constant was investigated. A full optimization of hexagonal lattice parameters and fractional coordinates of ScMnO_3 was performed with B3LYP for both the FM and the AFa states, [637]. The energy difference between these two states is reduced by 20% (compared with that obtained for the experimental structure) and J_a accordingly decreases to 11.2 meV. Since this value is still considerably larger than the estimated one the above statement about the inaccuracy of the linear interpolation scheme holds. In Table 9.24 there are also compared the calculated self-consistent magnetic moments μ_{eff} with the experimental value $4.11 \mu_B$ [632]. The obtained values range from 3.5 (BLYP) to $4.0 \mu_B$ (UHF) and are thus in agreement with experiment. The small change from 3.7 to $3.8 \mu_B$ due to optimization at the B3LYP level indicates that the local atomic structure has a small effect on this property. Atomic charges were calculated based on the Mulliken population analysis. Table 9.24 shows that the ionicity is reduced in the series from UHF to BLYP. The oxygen and manganese charges range from -1.2 to -1.5 and $+1.9$ to $+2.4$, respectively, indicating substantial covalent contributions to the bonding. These values do not essentially differ from those (-1.6 to -1.8 and $+1.5$ to $+1.8$), obtained in the LaMnO_3 calculations [623]. The PDOS calculated for ScMnO_3 with B3LYP for the fully optimized structure of the AFa state shows the following. The highest-occupied states between -0.5 and 0 eV (the Fermi level is taken as the zero energy), and the lowest-unoccupied bands between 3.3 and 4.5 eV consist of a mixture of $\text{O}(2p)$ and $\text{Mn}(3d)$ orbitals. Sc orbitals only contribute to higher unoccupied states above 5 eV. In agreement with experimental estimates [633], the interband transition at 3.3 eV with B3LYP was found. On the basis of the calculated PDOS the excitation is neither a pure $d-d$ nor a charge-transfer transition, rather it represents an intermediate situation.

As is seen from Table 9.24 the structure-parameter optimization influences the results of the electronic-structure calculations. Such an optimization also allows the calculation of the such important properties of solids as the cohesive energy, relative stability of phases with different structure, bulk moduli, and elastic constants. LCAO calculations of these total energy related properties are considered in the next section.

9.3 Total Energy and Related Observables in LCAO Methods for Solids

9.3.1 *Equilibrium Structure and Cohesive Energy*

The theoretical determination of the equilibrium structure of molecules and periodic systems and their cohesive energy is of primary importance in quantum chemistry of molecules and solids.

In the molecular systems, the parameters that must be optimized are the nuclear coordinates. Such an optimization requires the numerical or analytic calculation of forces—the total energy derivatives with respect to nuclear coordinates. The methodology for calculating analytic first derivatives at the HF (SCF) LCAO level of theory was suggested by Pulay [640]. Extensions of the HF derivatives to density-functional theory methods were straightforward. Derivatives of correlated (post-HF) energies followed a number of years after the SCF derivatives [641]. Analytical gradients have become a standard tool for the optimization of molecular structures and are implemented in modern molecular electronic-structure codes. Calculations with the structure optimization are now possible on molecules with hundreds of atoms, and energy derivatives provide an enormous amount of information about the potential-energy surface at very little additional cost. Analytic derivatives with respect to geometrical parameters are used not only for the structure optimization but also for exploring potential-energy surfaces and the study of transition states and following reaction paths.

Such molecular properties as vibrational frequencies, IR and Raman intensities, and NMR shielding constants can be formulated in terms of second and higher derivatives with respect to geometry and applied fields. Such calculations are now practical and routine using analytic derivatives at the SCF level and a few correlated methods, [641].

In periodic systems, the cell dimensions are a set of optimized structure parameters additional to nuclear coordinates in the primitive unit cell. Nowadays, the majority of solid-state codes compute the total energy with KS PW methods. In KS PW calculations the analytical gradients of total energy for nuclear coordinates and cell-parameter optimization are implemented in computer codes and widely used in the electronic-structure calculations of crystals [365]. The more complicated task is the analytical gradients theory in LCAO methods for periodic systems. The total energy E of the crystal (per primitive cell) is the sum of electron energy E_e and nuclear repulsion energy E_N : $E = E_e + E_N$. The electron energy E_e as calculated within the HF LCAO approximation can be expressed in terms of the one-electron-density matrix and includes the direct lattice sums, see (7.46). In the KS LCAO method only the electron-density is involved in the Hamiltonian, see (7.47).

The analytical gradients in HF and MP2 LCAO calculations were applied for a long time only for one-periodic (1D) systems [642, 643]. The efficient method of analytic energy-gradient calculation in the KS LCAO method for periodic

systems with one-, two- and three-dimensional periodicity was presented only recently in [77] and implemented in the code GAUSSIAN03 [102]. A real-space approach is used, where all the summations are performed in direct space. Energy derivatives with respect to geometrical parameters (atomic forces and stress tensor) are computed analytically to high accuracy using techniques based on the fast multipole method (see Chap. 7). This allows for the accurate lattice parameters and nuclear-coordinate optimization and evaluation of vibrational frequencies using finite differences of analytic forces. The extension of this technique to the hybrid HF–DFT LCAO Hamiltonians allowed optimization of the structure of different solids in good agreement with experiment (as was demonstrated in Chap. 7).

Simultaneously, progress has been achieved to implement analytical HF gradients in the LCAO code CRYSTAL [21, 644]. The formulas for analytic total-energy gradients with respect to nuclear coordinates in periodic systems were presented in [645, 646] and illustrated in test calculations. It was demonstrated that an efficient nuclear-coordinates optimization of large systems with any periodicity can be performed. Later, the theory of analytical HF gradients with respect to the cell parameter for three-periodic systems was presented [647], so that full structure optimization with the help of analytical gradients is now possible. It is important to note that the CRYSTAL code is based on the Ewald method in three dimensions, so that computing analytical gradients with respect to the cell parameter requires various additional derivatives that were not yet available with the implementation of nuclear gradients, and this has been documented in great detail in [647]. The one- and two-dimensional cases are again different because different potentials are used in a real-space approach. The article [648] complements [647] by analytical HF gradients with respect to cell parameters for systems periodic in one and two dimensions. The implementations mentioned include the cases of spin-restricted and unrestricted polarization.

We intentionally do not give here the mathematical details of the approaches allowing implementation of analytical gradients in the calculations of periodic systems (for these details readers are referred to the cited publications and references therein). We note that such an implementation is essentially more complicated than in the case of molecular systems and requires high accuracy in the total-energy calculation. One can find the detailed analysis of the accuracy in gradients calculations on numerical examples in [644, 645, 647]. The comparison of the numerical and analytical derivatives values can also be found. In what follows we turn to the results obtained for the equilibrium structure and cohesion energy in the crystalline metal oxides. The LCAO calculations discussed were made with the CRYSTAL code and use of HF, KS and hybrid Hamiltonians.

The cohesive (binding) energy E_{coh} is defined as the energy required to dissociate a solid into noninteracting atomic species A with energies E_A

$$E_{\text{coh}} = \sum_A E_A - E_{\text{solid}} \quad (9.82)$$

In this definition, E_{coh} is positive for any thermodynamically stable crystal. The summation is made over the atoms included in the primitive unit cell, E_{solid} is the total energy per primitive cell. Calculated values of the cohesive energy are compared with experimental results that can be obtained by measuring the latent heat of sublimation at various low temperatures, and extrapolating to zero Kelvin.

The binding-energy definition depends on what the constituent parts are considered to be: reference can be made to the ions in ionic crystals or to the molecules for molecular crystals. The expression “lattice energy” is also in use either as a synonym of cohesive energy or to denote the energy difference relative to the free ions or molecules [552]. In the calculations of E_{coh} we are interested not in the total energy of a system as such, but rather in energy differences that might be as small as a few kcal/mol. It is with respect to this scale of energy that the overall accuracy of a calculation must be verified. The molecular codes now allow an accuracy of 1 kcal/mol for thermochemical data, which is still far from being attained in solid-state chemistry, although attention to the quantitative aspects of the calculation is increasing rapidly, [552]. The different computational aspects of the ground-state total-energy evaluation for crystals are considered in [649]. In particular, some sources of errors in the total-energy calculations are analyzed: (1) the choice of Hamiltonian (HF, DFT, HF+ a posteriori correlation correction, description of the core electrons by one or other pseudopotential); (2) the use of a finite variational basis; (3) the numerical approximations, introduced in the solution of LCAO equations (truncations of infinite lattice sums, reciprocal-space integration). In the evaluation of the cohesive energy, partially different basis sets for the valence or semicore states need to be used for the atoms or ions and the bulk crystal. The bulk basis set can be improved by the addition of polarization functions, which do not contribute to the energy of atoms and ions in the gas phase because of AO orthogonality, but they can be important in the expansion of the bulk wavefunction. The atomic function tails become unnecessary in the description of the crystalline orbitals. Moreover, the use of diffuse AOs is normally to be avoided (see Chap. 8). Thus, separate optimizations of basis set for the bulk and the isolated atoms are necessary, *that is*, not equal, but variationally equivalent basis sets are to be used. The handling of these problems in the cohesive-energy calculation is illustrated in [552] and the general influence of the Hamiltonian choice on the calculated cohesive energy is discussed. An important aspect of the comparison between the calculated and experimental cohesive energy is related to the difference between the definition of cohesive energy and the crystal-formation energy that is reported in thermodynamic tables, the main point probably being that quantum-mechanical calculations refer to the static limit ($T = 0$ K and frozen nuclei), whereas experiments refer to some finite temperature. In fact, the comparison is never straightforward, and the original experimental datum is linked to the calculated cohesive-energy values through a chain of thermodynamic transformations. As an example, the Born–Haber cycle for the formation of a crystal has to be considered (see below).

Table 9.25 The equilibrium structure and cohesive energy for rutile TiO_2 [650]. Lattice parameters are given in Å, cohesive energy in eV

Observable	HF (AE) ^a	HF(PP) ^a	HF+correlation	Experiment
a	4.559	4.555	4.548	4.592
c	3.027	3.024	2.993	2.958
u	0.3048	0.3061	0.3046	0.3048
E_{coh}	13.95	15.99	19.35	20.00

^a Reference [580]

A general feature of the HF LCAO method is the underestimation of the cohesive energy (the error varies between -20 and -45% for the series of compounds considered in [552]). DFT calculations of E_{coh} allow one to recover part of the contributions that are disregarded with HF, at about the same computational cost. LDA even tends to overestimate the cohesive energy, whereas GGA and B3LYP results are closer to the experimental measurements. At any rate, the performance of none of the Hamiltonians used is fully satisfactory, and the correct answer is always somewhere in between the two extremes represented by HF and LDA, but LDA results are generally improved when gradient corrections are included. Properly correlated wavefunctions perform better than HF and DFT methods: the binding energies for the incremental scheme and local MP2 methods (see Chap. 5) agree better with the experimental data.

As an example, we give in Table 9.25 the results obtained for equilibrium structure and cohesive energy in rutile TiO_2 by different LCAO methods [650]. For the correlation calculations in [650] an incremental scheme was used, one-, two- and three-atom clusters in a large slab of Madelung point charges were included in the CCSD calculations. For the Ti ions nearest to the cluster atoms Ti^{4+} pseudopotentials were used instead of the bare point charges, in order to simulate the Pauli repulsion on the O^{2-} electrons of the inner cluster. The cohesive energy was calculated including zero-point vibrations (see Sect. 9.3.3). As is seen from Table 9.25 the electron correlation for TiO_2 crystal does not influence the equilibrium structure parameters in a major way but is important for the cohesive energy.

In Table 9.26, a summary of the results from a selection of experimental and recent *ab initio* studies of the structural parameters of rutile is presented, see [581]. Early LCAO HF and PW-LDA studies of rutile yielded lattice parameters to within 2% of experiment. More recent studies that have taken advantage of improvements in the theoretical techniques and available computing power to perform calculations with improved treatments of exchange and correlation (DFT calculations based on the GGA) and higher numerical accuracy improved basis sets have yielded results consistent with those from the earlier work.

Generally speaking, all the *ab initio* studies of rutile have yielded structural parameters to within a few per cent of experiment. In particular, LCAO methods give results with the same accuracy as PW methods.

Table 9.26 The theoretical and experimental structural parameters for rutile (in Å), numbers in parentheses indicate the percent deviation from low-temperature neutron-diffraction experiments. The references to the theoretical and experimental data, given in this table, can be found in [581]. SC, LC mean small-core and large-core pseudopotentials, AE—all-electron calculations

Method	<i>a</i>		<i>c</i>		<i>u</i>	
PW-LDA SC	4.555	(−0.70)	2.922	(−1.08)	0.304	(−0.33)
PW-LDA SC	4.528	(−1.29)	2.918	(−1.21)	0.303	(−0.66)
PW-LDA SC	4.567	(−0.44)	2.932	(−0.74)	0.305	(0.00)
PW-LDA LC	4.536	(−1.11)	2.915	(−1.32)	0.304	(−0.33)
PW-LDA LC	4.653	(1.44)	2.966	(0.41)	0.305	(0.00)
PW-LDA LC	4.603	(0.35)	2.976	(0.74)	0.304	(−0.33)
PW-LDA LC	4.638	(1.11)	2.923	(−1.05)	0.305	(0.00)
PWGGA LC	4.624	(0.81)	2.992	(1.29)	0.305	(0.00)
PWGGA LC	4.690	(2.25)	2.990	(1.22)	0.306	(0.33)
OLCAO-LD AE	4.622	(0.77)	2.983	(0.99)	0.304	(−0.33)
LCAO HF LC	4.555	(−0.70)	2.998	(1.49)	0.306	(0.33)
LCAO HF AE	4.560	(−0.59)	3.022	(2.30)	0.305	(0.00)
LCAO HF AE	4.529	(−1.26)	3.088	(4.54)	0.305	(0.00)
LCAO HF AE	4.548	(−0.85)	2.993	(1.32)	0.305	(0.00)
LCAO LDA AE	4.529	(−1.26)	2.942	(−0.41)	0.304	(−0.33)
X-ray 298 K	4.594	(0.15)	2.958	(0.14)	0.305	(0.00)
Neutron 295 K	4.593	(0.13)	2.959	(0.17)	0.305	(0.00)
Neutron 15 K	4.587		2.954		0.305	

Table 9.27 Calculated and experimental binding energies (eV) of corundum-like oxides [583]

Oxides	UHF	UHF+corr	Experiment
Al ₂ O ₃	−23.64	−30.08	−32.14
Ti ₂ O ₃	−21.41	−28.05	−33.45
V ₂ O ₃	−19.28	−26.23	−31.21
Cr ₂ O ₃	−18.10	−25.08	−28.05
Fe ₂ O ₃	−17.46	−22.00	−25.17
Co ₂ O ₃	−19.80	−24.90	—
Ni ₂ O ₃	−17.41	−22.74	—

Table 9.27 shows the results of binding-energy HF LCAO calculations [583] in corundum-like Me₂O₃ oxides (M=Ti,V,Cr,Fe,Co,Ni). The a posteriori DFT correlation correction of total energy was added in the UHF LCAO AE calculations with numerical optimization of corundum structure parameters.

The atomic energies of Al, Ti, V, Cr, Co, Ni and oxygen were derived by using the basis sets adopted for solid oxides, but supplemented by two more diffuse shells, the exponents of which were optimized. The binding energy is computed as the difference between the total crystal energy per formula unit (for the most stable antiferromagnetic configuration) and the energies of the constituent isolated atoms. For comparison, experimental binding energies are also given. These were obtained by applying a suitable Born–Haber thermochemical cycle of type

$$E_{\text{coh}}(\text{expt}) = \sum_i [H_{a,i}^0 + (H_i^{298} - H_i^0)] + \Delta_f H^{298} - (H^{298} - H^0) - E_{\text{vib}}^0 \quad (9.83)$$

Here, the sum is extended to all chemical elements in the formula unit. The formation enthalpy $\Delta_f H^{298}$ of Me_2O_3 compounds, sublimation (Me) and dissociation (O_2) enthalpies $H_{a,i}^0$ and heating enthalpies $H_i^{298} - H_i^0$ for all chemical species involved were taken from [651]. The zero-point vibrational energies E_{vib}^0 of all oxides were estimated by the Debye model, using an isotropic approximation for the mean acoustic-wave velocity derived from the bulk modulus in order to obtain the Debye temperature.

Table 9.27 shows that the general trend of experimental data (from Al_2O_3 to Fe_2O_3) is simulated correctly by theoretical binding energies, with deviations of the order of -30% for UHF energies, which are reduced to -12% by including the DFT-based correction for electron correlation. A secondary feature of the experimental data is not reproduced by the calculated results: the peculiar stabilization energy of Ti_2O_3 with respect to other oxides. Also, V_2O_3 seems to be affected by a larger error than the average. This is consistent with the difficulties found in achieving SCF convergence to stable insulating states for these two oxides: oxides of early-row transition metals, with their very diffuse d orbitals and tendency to metal states, are harder to simulate by HF methods than those of end-row metals. As we have seen in Sect. 9.1 the UHF calculations of Ti_2O_3 reproduce the electron correlation effects on the local properties of chemical bonding. It appears that a posteriori correction of UHF total energy is not enough to reproduce the correlation effects on the binding energy, *that is*, self-consistent hybrid HF–DFT calculations are required.

In the next section we consider the LCAO calculations of other total-energy-related observables.

9.3.2 Bulk Modulus, Elastic Constants, and Phase Stability of Solids: LCAO *Ab Initio* Calculations

We considered above the calculation of observables requiring the first-order derivatives of the total energy. For the equilibrium structure of crystal (equilibrium nuclear coordinates and unit-cell parameters) the total-energy derivatives with respect to nuclear coordinates $\mathbf{r}$ and lattice parameters $\mathbf{a}_i$ equal zero at constant temperature T : $\left(\frac{\partial E}{\partial \mathbf{r}_i}\right)_T = 0$, $\left(\frac{\partial E}{\partial \mathbf{a}_i}\right)_T = 0$.

An important variable is pressure as under pressure interatomic distances in crystals show larger variations than those induced by temperature. At constant temperature T pressure P is related to the rate of energy change with the unit-cell volume V by relation $P = -\left(\frac{\partial E}{\partial V}\right)_T$, including the first-order derivative of total energy with respect to the cell volume. Such observables as the bulk modulus, the elastic and force constants depend on the second-order derivatives of the total energy.

Table 9.28 Calculated lattice constant a (Å), interatomic distances (Å), bulk modulus (GPa) and elastic constants (GPa) for Cu₂O [606]

	HF	HF+LYP	Expt.
a	4.435	4.277	4.2696
Cu–O	1.920	1.852	1.849
Cu–Cu	3.136	3.025	3.012
B	100	93	112
C_{11}	118	103	116–126
C_{12}	90	88	105–108
C_{44}	59	65	11–13

The bulk modulus B measures the response of a crystal to *isotropic* lattice expansion or compression and can be related to the second-order derivative of the total energy with respect to the volume, V , evaluated at the equilibrium volume V_0 :

$$B = -V \left(\frac{\partial P}{\partial V} \right)_T = -V \left(\frac{\partial^2 E}{\partial V^2} \right)_{V_0} \quad (9.84)$$

The *anisotropic* response of a crystal to a mechanical force can be described by the elastic constants, C_{ij} , which are defined as the second derivatives of the total energy with respect to the components ε_i and ε_j of the strain tensor, ε :

$$C_{ij} = \left(\frac{\partial^2 E}{\partial \varepsilon_i \partial \varepsilon_j} \right)_{\text{eq}} \quad (9.85)$$

The strain-tensor components $\varepsilon_{ij} = \frac{1}{2} \left(\frac{\partial u_i}{\partial x_j} + \frac{\partial u_j}{\partial x_i} \right)$ are first-order derivatives of the displacements u . The elastic constants provide a full description of the mechanical properties of crystalline materials. The bulk modulus is related to the elastic tensor. In the case of a cubic system, where only three independent components of the elastic tensor differ from zero, B can be obtained from C_{11} and C_{12} as $\frac{1}{3} (C_{11} + 2C_{12})$. Table 9.28 shows the results of the HF LCAO optimization of the Cu₂O crystal structure with the all-electron basis set [606]. These results show the feature noted above of the HF method—an overestimation of the lattice size, mainly due to the neglect of electronic correlation. The a posteriori inclusion of the electronic correlation considerably improves the results of the structure optimization.

The isotropic variation of the volume of the cubic unit cell was used also to evaluate the bulk modulus. The calculated bulk modulus is in good agreement with the available experimental data. The three independent components of the elastic tensor were derived numerically from the changes in energy obtained by applying adequate deformations to the unit cell. Good agreement has been obtained for the C_{11} and C_{12} elastic constants, while there is definite disagreement for C_{44} . This disagreement is certainly to be attributed to the lack of precision of these methods to estimate small values of the elastic constants. Good-quality calculations of the

elastic constants would require a larger accuracy, in contrast to those properties like the cell parameters.

Various possible structures of a crystal and the associated relative energies can be determined experimentally as a function of pressure. This structure evolution as a function of pressure can involve one (polymorphism) or several (solid-state reaction driven by pressure) types of systems. For example, CaO crystal phase transition $\text{CaO}(B_1) \rightleftharpoons \text{CaO}(B_2)$ includes two polymorphic phases B_1 (fcc lattice, Ca atom is sixfold coordinated) and B_2 (sc lattice, Ca atom is eightfold coordinated). The decomposition reaction of MgAl_2O_4 spinel into its oxide components $\text{MgAl}_2\text{O}_4 \rightleftharpoons \text{MgO} + \text{Al}_2\text{O}_3$ includes three types of system. The knowledge of pressure enables investigation of phase stability and transitions, [552]. In fact, enthalpy is immediately obtained from the total energy by $H = E + PV$ at $T = 0$ K, where any transformation of a pure substance tends to be isotropic, phase stability can be related to the enthalpy and a phase transition occurs at those points in the phase diagram where two phases have equal enthalpy. From the computational point of view, it is possible to explore a range of crystalline volumes by isometric lattice deformations and obtain the corresponding values of pressure and, consequently, of enthalpy. It is intended that nuclei are allowed to relax to their equilibrium geometry after every lattice deformation.

The theoretical study of phase transitions is made as follows. For each crystal phase, the total energy E is computed at a number of unit-cell volumes V ; at each volume, the structure parameters (nuclear coordinates and lattice parameters) that minimize E are determined. An analytical representation of E vs. V is obtained by using a polynomial expression or the Murnaghan equation of state (or any other fitting function). The Murnaghan function, by far the most universally adopted, is as follows:

$$E(V) = E_0 + B_0 V_0 \left[\frac{1}{B'(B' - 1)} \left(\frac{V_0}{V} \right)^{B' - 1} + \frac{V}{B' V_0} - \frac{1}{B' - 1} \right] \quad (9.86)$$

The four fitting parameters are V_0 (equilibrium volume), B_0 (zero-pressure bulk modulus) and B' (pressure derivative of the bulk modulus B at $P = 0$), and E_0 (equilibrium energy). From the $P(V) = -\frac{\partial E}{\partial V}$ relationship, we get

$$V(P) = V_0 \left(\frac{B'}{B_0} P + 1 \right)^{-\frac{1}{B'}} \quad (9.87)$$

Inserting (9.87) in (9.86), one obtains the analytic E vs. P dependence; by adding the PV term, the enthalpy as a function of pressure is obtained:

$$H(P) = E + PV = E_0 + \frac{B_0 V_0}{B' - 1} \left[\left(\frac{B'}{B_0} P + 1 \right)^{1 - \frac{1}{B'}} - 1 \right] \quad (9.88)$$

At $T = 0$ K, the transition pressure, P_t , corresponds to the point where all the systems have the same enthalpy:

$$\Delta H(P_t) = 0 \quad (9.89)$$

This equation is solved numerically yielding the transition or the decomposition pressure. Knowing this pressure, the equation of state followed by the system during the process can be deduced.

A rough estimate of the transition pressure, P_t' , can be obtained just from the knowledge of the equilibrium values (E_0 and V_0) for each phase. At $T = 0$ K, the enthalpy as a function of pressure can be evaluated as follows:

$$H(P) = H_0 + \int_0^P dH = E_0 + \int_0^P V dP \quad (9.90)$$

Using this relation, (9.89) becomes

$$\Delta H(P_t) = \Delta E_0 + \int_0^{P_t} \Delta V dP = 0 \quad (9.91)$$

If the pressure dependence of ΔV is negligible, one obtains

$$P_t \approx P_t' = -\Delta E_0 / \Delta V_0 \quad (9.92)$$

For fitting of one or multiphase transitions MULFAS (multiphase transition analysis program) by Llundell can be used. The information about this program can be found at the site www.crystal.unito.it in tutorials (phase transitions) directory. An input file for this program contains the volume and total-energy data of one phase obtained by using an external quantum-mechanical or shell-model program.

The first-principles all-electron LCAO calculations of the crystal structures, bulk moduli, and relative stabilities of seven TiO_2 polymorphs (anatase, rutile, columbite, baddeleyite, cotunnite, pyrite, and fluorite structures) have been carried out in [581]. From the optimal crystal structures obtained with the Hartree–Fock theory at various pressures, the bulk modulus and phase-transition pressures of various high-pressure polymorphs have been derived at the athermal limit. In most cases, the calculated unit-cell data agree to within 2% of the corresponding experimental determination. In Table 9.29 the calculated bulk moduli of the various phases of TiO_2 are given and compared with the existing experimental data. The calculated bulk moduli are within 10% of the most reliable experimental results. It was shown in [581] that the computed anatase–columbite, rutile–columbite, columbite–baddeleyite, and baddeleyite–cotunnite phase transitions appear in the same order as observed in experiments, and the transition pressures agree semiquantitatively with

Table 9.29 The bulk moduli (GPa) of various phases of TiO₂ compound [581]

	Rutile <i>P4₂/mm</i>	Anatase <i>I4/amd</i>	Columbite <i>Pbcn</i>	Baddeleyite <i>P2₁/c</i>	Pyrite <i>Pa$\bar{3}$</i>	Fluorite <i>Fm$\bar{3}m$</i>	Cotunnite <i>Pnma</i>
Method	<i>Z</i> = 2	<i>Z</i> = 2	<i>Z</i> = 4	<i>Z</i> = 4	<i>Z</i> = 4	<i>Z</i> = 1	<i>Z</i> = 4
LCAO HF	239±10	202±10	264±10	300±10	318±10	331±10	380±10
LCAO LDA	241±10	195±10	—	—	273±10	308±10	—
PW-LDA	243	194	247	249	—	282	—
experiment	211±7	178±1	253±4	304±6	—	—	431±10

those measured. The pyrite and fluorite structures are predicted to be less stable than other polymorphs at pressures below 70 GPa, in agreement with experiments.

The detailed LCAO calculations for bulk properties and the electronic structure of the cubic phase of SrTiO₃ (STO), BaTiO₃ (BTO), and PbTiO₃ (PTO) perovskite crystals with optimization of basis set (BS) are presented in [590]. The results given in Table 9.30 are obtained using *ab initio* Hartree–Fock (HF) and density-functional theory (DFT) with Hay–Wadt pseudopotentials. A number of different exchange-correlation functionals including hybrid (B3PW and B3LYP) exchange techniques are used. Results, obtained for seven types of Hamiltonians, are compared in Table 9.30 with available experimental data. On average, the disagreement between the lattice constants computed using hybrid HF–DFT functionals and experimental values for all three perovskites is less than 0.5%.

The bulk moduli were calculated in two ways—as the total-energy second derivatives (9.84), B_1 and using the elastic constants, B_2 . The results for both ways of bulk-moduli evaluation differ by no more than 10–15%. Especially good agreement with the experimental data has been achieved for hybrid functionals. With the polarization orbitals added to the BS of oxygen atom, the calculated optical bandgaps are 3.57, 3.42 and 2.87 eV for STO, BTO and PTO respectively, in very good agreement with experimental data.

We note that the results given in Table 9.30, were obtained with the BS optimization (the details of this optimization can be found in [590]). In our opinion, it is this optimization that allowed good agreement of calculated and experimental data to be obtained.

Strontium zirconate SrZrO₃ is of interest because of possible applications in fuel cells, hydrogen gas sensors and steam electrolysis. The powder neutron-diffraction data suggest the following sequence of phase transitions in SrZrO₃: from the orthorhombic *Pbnm* to the orthorhombic *Cmcm* at 970 K, to the tetragonal *I4/mcm* at 1,100 K and lastly, to the cubic *Pm $\bar{3}m$* at 1,400 K [652]. The first *ab initio* DFT PBE calculations for all four phases of SrZrO₃ using both PW and LCAO basis sets are presented in [598]. The structural parameter optimization was performed using DFT PBE-PW calculations and good agreement with experimental data was obtained. LCAO PBE calculations were made both for the experimental and optimized structures. Table 9.31 shows the calculated relative energies (per formula unit) of four SrZrO₃ polymorphs.

Table 9.30 The optimized lattice constants a (Å), bulk moduli B (GPa) and elastic constants C_{ij} (in 10^{11} dyn/cm²) for perovskites SrTiO₃ (STO), BaTiO₃(BTO), PbTiO₃(TO), [590]

Method	LDA	PWGGA	PBE	BLYP	P3PW	B3LYP	HF	Exper.
STO								
a	3.86	3.95	3.94	3.98	3.90	3.94	3.92	3.89
C_{11}	42.10	31.29	31.93	29.07	31.60	32.83	41.7	31.72
C_{12}	12.21	9.80	9.75	9.39	9.27	10.57	7.11	10.25
C_{44}	13.32	11.34	11.30	11.09	12.01	12.46	10.5	12.35
B_1	222	170	171	159	167	180	186	174
B_2	214	167	169	164	177	177	219	179
BTO								
a	3.96	4.03	4.03	4.08	4.01	4.04	4.01	4.00
C_{11}	35.81	30.11	31.04	28.22	31.12	29.75	30.1	20.60
C_{12}	11.52	10.35	10.72	10.78	11.87	11.57	13.46	14.00
C_{44}	14.98	13.22	13.98	12.24	14.85	14.54	17.34	12.60
B_1	196	169	175	166	183	176	190	162
B_2	204	175	180	154	188	172	194	195
PTO								
a	3.93	3.96	3.96	4.02	3.93	3.96	3.94	3.97
C_{11}	45.03	32.47	34.25	23.03	43.04	34.42	39.83	22.9
C_{12}	26.14	15.81	15.52	9.93	24.95	18.08	16.90	10.1
C_{44}	11.28	10.69	10.96	8.25	10.93	10.35	17.20	10.0
B_1	324	213	217	143	310	235	245	144
B_2	321	246	252	140	279	242	299	

Table 9.31 Calculated relative energies (eV per formula unit) of SrZrO₃ polymorphs [598]

Phase	Structure parameters		
	Exper.	Optimized	
	LCAO	LCAO	PW
$Pm\bar{3}m$	0.000	0.000	0.000
$I4/mcm$	−0.040	0.002	0.004
$Cmcm$	−0.177	−0.252	−0.235
$Pbnm$	−0.241	−0.303	−0.274

It is seen from Table 9.31 that both LCAO and PW results agree with the experimental sequence of the SrZrO₃ phases: the most stable turn out to be two orthorhombic phases, whereas the tetragonal and cubic high-temperature phases are close in energy.

The sequence of phase transitions in ABO₃-type oxides with the temperature increase could be described in terms of the nearest BO₆ octahedral tilts/rotations [652]. In the SrZrO₃ case, the orthorhombic structure with three rotations is changed by two rotations for *Cmcm* and finally by one rotation for the tetragonal structure. The combination of three rotations produces the lowest-energy structure. The electrostatic energy is lowest for the lowest symmetry because of the inherent instability of the ideal corner-shared octahedral network. To compensate the loss

in Madelung energy, the repulsive energy should also be lowered, in order to achieve the equilibrium. Thermal expansion or entropy is the driving force for the octahedral tilts.

9.3.3 Lattice Dynamics and LCAO Calculations of Vibrational Frequencies

The second-order derivatives of the energy with respect to the nuclear coordinates are involved in lattice dynamics, in particular, in the calculation of vibrational (phonon) spectra. We shall begin from the molecular case, [653]. The decoupling of the nuclear from the electronic motion is made in the adiabatic approximation (see Chap. 4). Let u_i represents a displacement of the i th Cartesian coordinate from its equilibrium value ($i = 1, 2, \dots, 3N$), where N is the number of nuclei in a molecule, and $q_i = \sqrt{M_i}u_i$ are the generalized coordinate (M_i is the mass of the atom associated with the i th coordinate) and its derivative with respect to time $\dot{q}_i = \dot{p}_i$. In the harmonic, approximation the classical vibrational Hamiltonian of a polyatomic molecule becomes

$$H = T + V = \frac{1}{2} \left(\sum_i M_i \dot{u}_i^2 + \sum_{ij} H_{ij} U_j \right) + V_0 = \frac{1}{2} (\langle p|p \rangle + \langle q|W|q \rangle) + V_0 \quad (9.93)$$

Here V_0 is the electron energy for the equilibrium atomic coordinates, and H_{ij} are the Hessian matrix elements

$$H_{ij} = \frac{1}{2} \left[\frac{\partial^2 V}{\partial u_i \partial u_j} \right]_0 \quad (9.94)$$

evaluated at equilibrium. The relation $W_{ij} = \frac{H_{ij}}{\sqrt{M_i M_j}}$ defines the elements of the weighted Hessian.

The eigenvalues κ_j of the Hermitian matrix W are the generalized force constants. The Hamiltonian (9.93) then can be factorized into $3N$ one-dimensional harmonic Hamiltonians

$$H = \sum_v h_v = \sum_v \frac{1}{2} (P_v^2 + \omega_v^2 Q_v^2) \quad (9.95)$$

Thus each of the $3N - 6$ vibrational modes can be interpreted as a collective oscillatory movement with frequency $\omega_v = \sqrt{\kappa_v}/2\pi$ and the problem of calculating vibrational spectra reduces to the diagonalization of matrix W to find the set of eigenvalues κ_j .

For periodic systems, the translation invariance of the potential energy and Hessian matrix should be used. The generalized coordinates obey the Bloch theorem and are written in the form

$$q_i(\mathbf{k}) = N \sum_{\mathbf{g}} \exp(-i\mathbf{k} \cdot \mathbf{g}) q_i^{\mathbf{g}} \quad (9.96)$$

The vibrational problem is block-factorized into a set of problems (one for each $\mathbf{k}$ point in BZ) of dimension $3N - 6$ where N is the number of atoms in the primitive unit cell.

The $\mathbf{k}$ -block of the $\mathbf{k}$ -factorized W matrix takes the form

$$W_{ij}(\mathbf{k}) = \sum_{\mathbf{g}} \exp(i\mathbf{k} \cdot \mathbf{g}) \frac{H_{ij}^{0\mathbf{g}}}{\sqrt{M_i M_j}} \quad (9.97)$$

where $H_{ij}^{0\mathbf{g}}$ is the second derivative of potential energy at equilibrium with respect to atom i in the reference cell $\mathbf{0}$ and atom j in cell $\mathbf{g}$. The number of equations (9.97) to be solved equals the number of $\mathbf{k}$ -points in the BZ, *that is*, is infinite for the infinite crystal. In practice, the calculations of phonon frequencies are made for a finite number of $\mathbf{k}$ -points and the interpolation is used to obtain so-called phonon branches $\omega_1(\mathbf{k}), \dots, \omega_i(\mathbf{k}), \dots, \omega_{3N}(\mathbf{k})$ (like one-electron energies are obtained in SCF calculations for a finite set of $\mathbf{k}$ -points and then interpolated to form the electron energy bands). The relationship between phonon frequencies ω and wavevector $\mathbf{k}$ determines the phonon dispersion.

Comparing the vibrational branches and electronic bands calculations we note that in the former case the equations for different $\mathbf{k}$ values are solved independently while in the latter case the self-consistent calculation is necessary due to the BZ summation in the HF or KS Hamiltonian (see Chaps. 4 and 7). Once the phonon dispersion in a crystal is known, thermodynamic functions can be calculated on the basis of statistical mechanics equations. As an example, the Helmholtz free energy, F , can be obtained as:

$$\langle F \rangle = \sum_{i\mathbf{k}} \left\{ \frac{1}{2} \hbar \omega_{i\mathbf{k}} + k_B T \ln \left[1 - \exp \left(-\frac{\hbar \omega_{i\mathbf{k}}}{k_B T} \right) \right] \right\} \quad (9.98)$$

where the sum is extended to all lattice vibrations, $\omega_{i\mathbf{k}}$, and k_B is the Boltzmann's constant. Another way of computing thermodynamic functions is based on the use of the phonon density of states. The evolution of the crystal structure as a function of temperature and pressure can also be simulated by minimizing $G = F + pV$. The procedure requires a sequence of geometry optimizations, and lattice-vibration calculations [552].

Lattice vibrations can be measured experimentally by means of classical vibration spectroscopic techniques (infrared and Raman) or neutron inelastic scattering. However, only the latter technique allows one to measure the full spectrum in a range

Table 9.32 Phonon symmetry in rutile TiO_2 crystal with space group D_{4h}^{14}

q-basis		k-basis					
G_q	Rep. of G_q	Γ	M	Z	A	X	R
Ti(2a)	$b_{1u}(z)$	$2^-, 3^-$	$2^-, 3^-$	1	1	1	1^-
(000)	$b_{2u}(x - y)$	5^-	5^-	3	3	2	1^-
D_{2h}	$b_{3u}(x + y)$	5^-	5^-	4	4	2	1^-
O(4f)	$a_1(x + y)$	$1^+, 4^+, 5^-$	$1^+, 4^+, 5^-$	1,4	1,4	2,2	$1^+, 1^-$
(xx0)	$b_2(x - y)$	$2^+, 3^+, 5^-$	$2^+, 3^+, 5^-$	2,3	2,3	2,2	$1^+ 1^-$
C_{2v}	$b_1(z)$	$2^-, 3^-, 5^+$	$2^-, 3^-, 5^+$	1,3	1,3	1,1	$1^+ 1^-$

of $\mathbf{k}$ vectors, whereas with infrared and Raman spectroscopy, only lattice vibrations at $\Gamma(\mathbf{k} = \mathbf{0})$ are usually detected (the second-order spectra, corresponding to nonzero wavevector $\mathbf{k} \neq \mathbf{0}$ are demanding). The calculations of the vibrational frequencies only at Γ point require the solution of only one equation

$$\det |W(0)| = 0, \quad W_{ij}(0) = \sum_g \frac{H_{ij}^{0g}}{\sqrt{M_i M_j}} \quad (9.99)$$

To analyze the symmetry of phonon states the method of induced reps of space groups can be used [13]. The procedure of analysis of the phonon symmetry is the following. First, for the space group G of a given crystal the simple induced reps are generated (see Chap. 3). Second, using the simple induced reps together with the compatibility relations and arranging atoms in the primitive cell over the Wyckoff positions one can determine the symmetry of the phonons. Only those of the induced reps that are induced by the irreps of the site-symmetry groups according to which the components of the vectors of the local atomic displacements transform are used. The total dimension n of the induced rep (called the mechanical representation) equals $3N$ (N is the number of atoms in the primitive cell).

As an example, Table 9.32 shows the phonon symmetry in rutile TiO_2 crystal. The results given are easily obtained from the simple induced reps of the space group D_{4h}^{14} (see Table 4.5 in [13]) and the atomic arrangement in rutile TiO_2 (see Chap. 2).

There is a one-to-one correspondence between irreps of crystal point group D_{4h} and irreps of the space group at Γ point: $A_{1g,u} - 1^\pm$, $A_{2g,u} - 3^\pm$, $B_{1g,u} - 2^\pm$, $B_{2g,u} - 4^\pm$, $E_{g,u} - 5^\pm$. The atomic displacements of six atoms in the primitive cell generate the 18-dimensional reducible representation, which contains three acoustic modes and 15 optical modes ($A_{1g} + A_{2g} + A_{2u} + B_{1g} + 2B_{1u} + B_{2g} + E_g + 3E_u$). Three acoustic modes have zero frequency at the Γ point and are associated with the translation of the entire crystal along any direction in space. These branches are called *acoustic* modes as the corresponding vibrations behave as acoustic waves. The translation of the entire crystal along the z-axis corresponds to irrep $3^-(A_{2u})$ at Γ point, translation in the plane $xy - 5^-(E_u)$.

Both acoustic modes are polar and split into transverse A_{2u} (TO) and longitudinal E_u (LO) with different frequencies due to macroscopic electric field. All other branches show finite nonzero frequencies at Γ and are known as optical modes, because they correspond to unit-cell dipole moment oscillations that can interact with an electromagnetic radiation.

In the model of a finite crystal the rotation of the entire crystal around the z - and xy -axis corresponds to the irreps 3^+ and 5^+ , respectively, including the displacements of only oxygen atoms, see Table 9.32. As seen from Table 9.32, the phonons of even symmetry ($1^+, 2^+, 3^+, 4^+, 5^+$) are connected only with the oxygen-atom displacements. Due to the different atomic masses of oxygen and titanium atoms, the corresponding lines can appear in different parts of the vibrational spectra, making its interpretation easier. The knowledge of phonon symmetry is useful in the analysis of infrared and Raman spectra of solids as the symmetries of active phonons in these spectra are governed by selection rules following from the symmetry restrictions imposed on the transitions matrix elements [13]. Using the symmetry of the phonons found one can establish which vibrational modes are active in the first- and second-order infrared and Raman spectra.

The calculation of phonon frequencies of the crystalline structure is one of the fundamental subjects when considering the phase stability, phase transitions, and thermodynamics of crystalline materials. The approaches of *ab initio* calculations fall into two classes: the *linear response* method [654] and the *direct* method, see [655] and references therein.

In the first approach, the dynamical matrix is expressed in terms of the inverse dielectric matrix describing the response of the valence electron-density to a periodic lattice perturbation. For a number of systems the linear-response approach is difficult, since the dielectric matrix must be calculated in terms of the electronic eigenfunctions and eigenvalues of the perfect crystal.

There are two variants of the direct method. In the frozen phonon approach the phonon energy is calculated as a function of the displacement amplitude in terms of the difference in the energies of the distorted and ideal lattices. This approach is restricted to phonons whose wavelength is compatible with the periodic boundary conditions applied to the supercell used in the calculations. Another approach of the direct method uses the forces $\left(\frac{\partial E}{\partial u_i}\right)_{\text{eq}}$ calculated in the total-energy calculations, derives from them the values of the force-constant matrices and hence the dynamical matrix and phonon-dispersion curves. The majority of calculations were performed based on DFT PW method, for example to study phonons in the rutile structure, [656]. The calculation of the vibrational frequencies of crystals was implemented in the LCAO CRYSTAL06 code (see www.crystal.unito.it) and applied to different oxides: quartz SiO_2 [653], corundum Al_2O_3 [657], calcite CaCO_3 [658].

In the LCAO approximation frequencies at Γ are evaluated in the direct method in the same way as for molecules [653]: a set SCF calculations of the unit cell are performed at the equilibrium geometry and incrementing each of the nuclear coordinates in turn by u (use of symmetry can reduce the number of the required calculations). Second-order energy derivatives are evaluated numerically. Obtaining

Table 9.33 Calculated and measured frequencies (in cm^{-1}) relative to the Γ -point of bulk TiO_2 rutile [660]^a

Mode	PBE	PW91	LDA	Neutrons	IR and Raman
Raman					
B_{2g}	774.3	780.9	824.7	825	827
A_{1g}	565.9	572.0	611.6	610	612 (611)
E_g (2)	429.2	434.2	463.2	445	447 (455)
B_{1g}	154.2	151.7	137.0	142	143 (143)
Silent					
A_{2g}	423.6	425.4	421.7	Not found	—
B_{2u}	357.5	363.4	393.0	406	—
B_{1u}	79.2	99.2	104.0	113	—
Infrared					
E_u (TO)	468.6	472.0	488.4	494	500
E_u (TO)	353.5	357.1	383.9	Not found	388
E_u (TO)	124.0	127.4	191.4	189	183
A_{2u} (TO)	186.3	47.1	154.4	173 (142)	167 (144)

^a The double degeneracy of the E_g mode is indicated by the label (2). The references to the experimental neutron-scattering and the infrared (IR) and Raman data are given in [660]. When available, the low-temperature ($T \sim 4$ K) experimental frequencies are reported in brackets

frequencies at wavevector symmetry points different from Γ would imply the construction of appropriate supercells (see Chap. 3). These supercells are chosen in the same way as was discussed in the electronic-structure calculations due to the one-to one correspondence between the supercell choice and the set of $\mathbf{k}$ -points equivalent to the Γ point in the reduced BZ. A finite range of interaction in the lattice sum (9.99) is assumed, usually inside the supercell chosen (compare with the cyclic-cluster model in the electronic-structure calculations). In the case of ionic compounds, long-range Coulomb effects due to coherent displacement of the crystal nuclei are neglected, as a consequence of imposing the periodic boundary conditions [653]. Therefore, $W_{ij}(0)$ needs to be corrected for obtaining the longitudinal optical (LO) modes [659]. For this reason, in some cases only transverse optical (TO) parts of the phonon spectrum are calculated as is done in the combined DFT PW–DFT LCAO lattice dynamics study of TiO_2 rutile [660]. The phonon frequencies computed in [660] for optimized crystal structure are reported in Table 9.33 and compared with experimental data.

The LDA frequencies are in excellent agreement with the experimental frequencies, especially if compared with the frequencies measured at low temperature ($T \sim 4$ K), when these data are available. The deviation between the LDA and experimental frequencies is $\sim 13 \text{ cm}^{-1}$ at most, and is often much smaller than that. For instance, the deviation drops to no more than $\sim 2 \text{ cm}^{-1}$ for the two stiffest modes, B_{2g} and A_{1g} , and it remains small also for several of the softer modes. Both PBE and PW91 results are much less satisfactory. With the exception of the B_{1g} mode, the GGA functionals systematically underestimate the LDA and measured frequencies. It is found in [660] that this discrepancy between LDA and GGA

results is mostly due to the difference in the equilibrium lattice parameters at zero pressure predicted by the functionals. The LDA frequency is the highest because LDA predicts the smallest equilibrium volume, and the PBE equilibrium volume is large enough to lead to an imaginary frequency.

All the results discussed were obtained within the plane-wave pseudopotential implementation of DFT. For all functionals, calculations were repeated for the equilibrium geometries, bulk moduli, and energy profiles along the ferroelectric TO A_{2u} mode with the all-electron LCAO scheme. Apart from slight quantitative differences, in all cases the all-electron LCAO calculations agree well with the plane-wave, pseudopotential results, confirming their independence of the particular numerical scheme used to implement DFT. We note that the hybrid HF–DFT LCAO calculations could in principle give better agreement with experimental data for phonon frequencies of rutile as was shown in the B3LYP LCAO calculations of the vibrational spectrum of calcite CaCO_3 , [658]. In this case the mean absolute error is less than 12 cm^{-1} (frequencies range from 100 to $1,600 \text{ cm}^{-1}$).

9.3.4 Calculations on Cubic $\text{Ba}(\text{Ti}, \text{Zr}, \text{Hf})\text{O}_3$ and Noncubic BaTiO_3

ABO_3 -type oxides such as barium titanate, zirconate, and hafnate [BaTiO_3 (BTO), BaZrO_3 (BZO), and BaHfO_3 (BHO)] are attractive for various technological applications in modern electronics, nonlinear optics, and catalysis [854, 856–858].

BTO has been widely investigated since the discovery of its ferroelectric properties. Because of the number of different ferroelectric phases and the ease of switching between them BTO is also of great technological interest. Intense experimental efforts aimed at the synthesis of ferroelectric nanostructures [855] (nanoparticles, nanowires, and nanotubes) based on BTO can be expected to further expand its applicability.

BZO has attracted a great deal of attention as a high-temperature protonic conductor with possible applications in fuel cells and hydrogen sensors. BHO gained wide interest as a ceramic material, a material with a high melting point, and because of its high thermal expansion coefficient and high- k dielectric capacitor. The temperature dependence of the phase behavior is different in these three crystals.

At high temperature, BTO is stable in a paraelectric cubic structure with five atoms per unit cell (space group $Pm\bar{3}m$). At lower temperatures, BTO has three phase transitions to ferroelectric phases. At 493 K, BTO undergoes a structural phase transition to a tetragonal (space group $P4mm$) ferroelectric phase. Below 278 and 183 K, BTO has an orthorhombic (space group $Am\bar{m}2$) and rhombohedral (space group $R\bar{3}m$) structure, respectively [859]. BZO and BHO have a perfect cubic structure $Pm\bar{3}m$ over a wide range of temperatures and do not undergo any structural phase transitions down to 2 K [859].

There exist numerous experimental data explaining BTO ferroelectric behavior. However, our knowledge of the nature of ferroelectric phase transitions in BTO was rather limited until first-principles DFT calculations were employed to study BTO lattice dynamics. The exact knowledge of the vibrational states of a solid is the key to the calculation of its thermodynamic properties as a function of the temperature [860]. This problem is solved in the first-principles density-functional theory (DFT) calculations of the electronic structure and phonon frequencies in crystals. Once the electronic (ground) state of a system of nuclei and electrons is found and the phonon frequencies are calculated, the free-energy temperature dependence can be analyzed to study the thermodynamic properties. Moreover, the first-principles calculations of total energies for small distortions of an ideal crystal with cubic perovskite structure permits an effective Hamiltonian construction for taking into account the anharmonic effects and treating the phase transitions in perovskites [861–863] using the methods of statistical mechanics. Basing on this approach, a temperature-pressure dependence phase diagram of BaTiO_3 was investigated [862]. However, concerning the applied DFT exchange-correlation functional, the authors [862] noticed that the results of effective Hamiltonian calculations are to be considered as reliable only at the qualitative level due to the well-known underestimation of the equilibrium volumes given by LDA, which brings about a systematic error in the location of the zero of pressure (see also the discussion below).

The first-principles full-potential linear augmented plane wave (LAPW) [864] and PW DFT [865–867] phonon spectra calculations on BTO cubic phase demonstrated its structural instability via soft modes with imaginary frequencies at the Brillouin-zone (BZ) symmetry points $\Gamma(0, 0, 0)$, $X(0, 0, 0.5)$, and $M(0, 0.5, 0.5)$.

Several DFT calculations have been reported on the electronic and atomic structure of bulk BZO [868–873]. The first-principles DFT calculations on phonons in BZO give contradictory results [869]. Indeed, the imaginary frequencies (instable modes) at the Γ point were not found in DFT calculations [870, 871] but appear in the results of other calculations [869]. The unstable mode at M was not found in [870, 871] but appears in the results of calculations [869] performed using also the DFT method. The unstable mode at R (0.5, 0.5, 0.5) was found in calculations from [869–871] which disagrees with the experimental data showing that BZO structure is cubic. It was concluded [869] that the examination of phonon instabilities and their consequences for structural symmetry are especially demanding of the quality of the exchange-correlation (XC) potential and pseudopotential. The small-core pseudopotential (transferable rather than inexpensive) should be taken.

The first DFT calculations of BHO mechanical, electronic, and optical properties were only recently [868, 874–877]. A DFT (LDA) phonon calculation was published in [874] for cubic BHO, and no imaginary frequencies were found, in agreement with the experimentally found stability of the cubic BHO.

First-principles DFT calculations of the electronic and structural properties of perovskites are based in most cases on the LDA for the XC part of the density functional and to a lesser extent on the semilocal general gradient approximation (GGA), mainly in the parametrization of Perdew–Burke–Erzerhof (PBE). It is well known that DFT in the LDA or the GGA is often better than the Hartree–Fock (HF)

model, as the essential error of HF arises from the fact that in the HF model, the exchange-correlation hole in a two-electron bond is too delocalized. The simple truth is not that the LDA or the GGA is particularly good, but that HF is rather poor in the two-electron chemical bond description. In the perovskites, such bonds arise between the transition metal and oxygen atoms, being important for the correct description of the crystal properties. To improve the LDA and GGA models, the orbital-dependent hybrid XC functionals (such as B3PW, B3LYP, and PBE0) are used. The B3PW and B3LYP functionals contain parameters that were optimized to fit the experimental data for molecules. In the past decade, these hybrid functionals have also been increasingly applied to solids [1145]. The PBE0 hybrid functional with the PBE exchange-correlation part is parameter-free as the percentage of the HF exchange mixing with the PBE exchange is found from the perturbation theory. The hybrid functionals have been applied to perovskites in very few cases [590,867,868,879,880]. Most hybrid functional applications to solids use the linear combination of atomic orbitals (LCAO) basis set, as is done for molecules. This is explained by the difficulties in the HF method formulation for the PW basis set. Only recently were hybrid functionals implemented in the PW VASP (Vienna Ab initio Simulation Package) code for solids [867]. The hybrid XC functionals provide electronic structure of solids in much better agreement with the experiment, in particular for the band gap, usually underestimated in DFT calculations and overestimated in the HF method (see Sect. 7.2). However, the question arises of whether there is any need for hybrid functionals in the ground-state calculations, in particular for phonon frequencies. After all, hybrid functionals are at least one order of magnitude more expensive than semilocal GGA functionals. As is stated in [867], apart from the band gaps (which are not ground-state properties), there are a few other properties that are clearly predicted better by the hybrid functionals. It was found in PW DFT calculations [867] that for $\text{Sr}(\text{Ba})\text{TiO}_3$, the ground-state structure of the distorted antiferroelectric phase is in better agreement with the experiment, and phonon modes are much more accurate for hybrid XC functionals. The LDA predicts good phonon frequencies if the frequencies are evaluated at the theoretically predicted equilibrium volume because of sizable error compensation (the LDA equilibrium volume is too small, but LDA frequencies at the experimental volume are too soft). The GGA drastically underestimates the phonon frequencies as a result of a too large equilibrium volume. A systematic comparison of DFT and hybrid XC functionals for prototypical ferroelectric oxides BaTiO_3 and PbTiO_3 was reported in [880]. It was demonstrated that the new hybrid B1-WC (hybrid functional with $B = 1$ and Wu-Cohen DFT exchange) functional allows one to obtain very good structural, electronic, and ferroelectric properties as compared to the experimental data for BaTiO_3 and PbTiO_3 . The hybrid B1-WC functional consists of a PBE correlation part and a WC exchange part, [881] which is the modified PBE exchange. The percentage of the exact exchange is defined by the parameter A , which is varied in calculations with the hybrid B1-WC functional. The best results were found in [881] for $A = 0.16$. This means that the use of the hybrid B1-WC functional introduces an additional parameter in the first-principles calculation. Meanwhile, the hybrid PBE0 functional is parameter-free

as the exchange percentage ($A = 0.25$) was found from the perturbation theory. The verdict on which hybrid functional is better for ABO_3 perovskites is still open to discussion and requires further theoretical investigations [867]. This functional has been shown to properly reproduce the properties of many strongly correlated systems, see, for example, [878].

The periodic LCAO approach was applied in [882] to calculate the ground-state properties and phonon frequencies for the three crystals $\text{Ba}(\text{Ti}, \text{Zr}, \text{Hf})\text{O}_3$ within the hybrid XC functional PBE0. It was shown that such first-principles calculations with basis set optimization and the use of the parameter-free hybrid exchange-correlation PBE0 functional are able to predict correctly the structural stability and phonon properties in the cubic perovskites under consideration. In agreement with the experimental data the structure instability was found for the cubic phase in the ferroelectric BaTiO_3 crystal. For the cubic phases of BaZrO_3 and BaHfO_3 crystals imaginary phonon modes are not found to be in agreement with their experimentally known stability up to 2 K.

The calculations [883] demonstrate that the use of the hybrid PBE0 exchange-correlation Hamiltonian allows reproducing the equilibrium volumes of the structural, electronic, dielectric and vibrational properties of paraelectric cubic and three ferroelectric (tetragonal, rhombohedral and orthorhombic) BTO phases in good agreement with the existing experimental data.

In these calculations the Gaussian basis set and small-core pseudopotentials (PP) were used for metallic atoms. In this case, $5s$, $5p$ and $6s$ orbitals of barium, $3s$, $3p$, $3d$, and $4s$ orbitals of titanium were treated as valence states. In $\text{Ba}(\text{Ti}, \text{Zr}, \text{Hf})\text{O}_3$ calculations [882] the pseudopotential (PP) of the Ba atom and the corresponding contracted Gaussian basis set were taken from the PPs library of the Stuttgart/Cologne group, (<http://www.theochem.uni-stuttgart.de/pseudopotentials/clickpse.html>) while the uncontracted Gaussian basis set and the small-core CRENL ECP [884] were used for the Ti atom. In the calculations [883], because of the increasing amount of computations for large supercells, the Hay–Wadt small-core PP [885] for both Ba and Ti atoms was chosen. The corresponding basis sets as well as the all-electron basis for the O atom were taken from [590], where they were optimized for SrTiO_3 and BaTiO_3 crystals. This approach uses pseudopotentials generated for atoms from the HF method, that is, not generated using the hybrid functionals employed in DFT LCAO calculations which is traditional. On the other hand, the DFT community working with the PW basis has always favored an alternative approach that involves the generation of the corresponding pseudopotentials for each XC functional. It can be argued [590, 880] that the HF pseudopotentials constitute a reasonable choice. The pseudopotentials used describe the interaction of core and valence electrons in good agreement with the results of all-electron calculations, as it was demonstrated for BaTiO_3 and PbTiO_3 crystals. The values of lattice constants and phonon frequencies obtained from Ti all-electron calculations are very close to those obtained using Ti HF pseudopotentials.

A very high accuracy is needed for the calculation of phonon frequencies as they are determined by the second derivatives of the total energy over atomic displacements. For this reason the Monkhorst–Pack scheme for the $12 \times 12 \times 12$

k-point mesh in the BZ was applied together with the tolerances 8, 8, 8, 8, 16 for the one-electron, Coulomb and exchange integrals calculations. Briefly speaking, these tolerances mean that during the direct lattice summations the one-electron integrals and two-electron Coulomb integrals of smaller than 10^{-8} are estimated by the multipolar expansion and two-electron exchange integrals of smaller than 10^{-16} are ignored. These tolerances are usually tight enough for good DFT results. The use of tighter tolerances might be necessary for dielectric constants calculations [886]. A very large grid (XXLGRID) was also used for DFT integration.

The calculations of phonon frequencies were based on the following procedure. First, the equilibrium geometry was found. In the cubic phase the lattice parameter, fully defining the structure, was optimized. In the ferroelectric phases the lattice parameters and fractional displacements of atoms with respect to the cubic location were optimized. Ionic and cell relaxations were performed with the convergence criterion for the forces on atoms set to 0.005 eV/Å. The threshold on the energy change between the optimization steps for the self-consistent cycles was 10^{-9} eV for both the structure optimization and the phonon frequency calculations. Second, high-frequency dielectric tensors were estimated using the coupled perturbed Hartree–Fock/Kohn–Sham method [886, 887]. This is a perturbative treatment that allows solving the Schrodinger equation in the presence of the electric field perturbation. Furthermore, this is a coupled method (in contrast with the sum over states method) that, by means of a self-consistent cycle, allows the wave function to relax under the effect of the bielectronic potential corrected for the presence of the electric field. Convergence is then evaluated on a dielectric tensor element and the self-consistent procedure stops when no relevant changes happen between two subsequent cycles. Third, the phonon frequencies were obtained by the frozen phonon method [655, 888] within the harmonic approximation at the optimized equilibrium lattice constant. The zone-center phonon frequencies (the eigenvalues of the dynamical matrix) are determined from the numerical second-order derivatives of the ground-state energy. To this purpose the total energy is calculated for fixed distortions of the crystal. The supercell approach is used to obtain the phonon frequencies at the nonzero wave vectors. The convergence of the phonon frequencies and dispersion curves in terms of the supercell size was studied in *ab initio* frozen phonon calculations [889] on an ionic LiF crystal. The longitudinal–transverse (LO–TO) splitting was found using the theoretical values of the high-frequency dielectric constants given in Tables 9.34 and 9.35.

The first-principle calculations of four known BTO phases with perovskite structure, using the LDA, PBE and PBE0 XC functionals within the same LCAO approach were made in [883]. BTO cubic phase properties obtained using different XC functionals are compared in Table 9.34. The results of the calculations [882], also given in Table 9.34, show that the basis set change does not affect the results considerably. The calculated values are also compared with the existing experimental data. As is seen from Table 9.34 the use of the hybrid PBE0 XC functional generally allows predicting the considered cubic BTO properties with a better accuracy than the other XC functionals considered. Especially, the superior agreement between the PBE0 and experimental results can be seen for the lattice

Table 9.34 Calculated bulk properties of the BaTiO₃ cubic phase; Q and Z are Mulliken and Born atomic charges, respectively. Phonon frequencies (cm⁻¹) are given at the Γ -point of BZ; TO—transverse, LO—longitudinal optical phonons^a

Property	Previous work ^[882]	This work			Experiment
	PBE0	LDA	PBE	PBE0	
Cell a (Å)	3.988	3.958	4.036	3.992	3.996 ^b
Bulk modulus B (GPa)	185	197	166	189	162 ^c
Cohesive energy E_{at} (eV)	29.9	38.45	32.70	30.77	31.6 ^c
Band gap E_{gap} (eV)	3.7	1.9	1.9	4.0	3.2 ^d
High-frequency					
dielectric constant, ϵ_{∞}	5.2	6.32	6.34	5.11	5.4 ^e
Q_{Ba}	1.90	1.78	1.77	1.80	
Z_{Ba}	2.60	2.74	2.71	2.68	2.9 ^f
Q_{Ti}	2.24	2.20	2.25	2.39	
Z_{Ti}	7.06	7.30	7.36	6.98	6.7 ^f
Q_{O}	-1.38	-1.33	-1.34	-1.40	
Z_{O1}	-5.64	-5.80	-5.89	-5.58	-4.8 ^f
Z_{O2}	-2.01	-2.12	-2.09	-2.04	-2.4 ^f
$\Gamma_4^-(T_{1u}) - TO_1$	281i	133i	240i	257i (263i)	soft
$\Gamma_4^-(T_{1u}) - TO_2$	196	193	175	191 (191)	181 ^g
$\Gamma_5^-(T_{2u}) - \text{silent}$	314	296	290	313 (305)	306 ^g
$\Gamma_4^-(T_{1u}) - TO_3$	478	483	460	483 (474)	487 ^g
$\Gamma_4^-(T_{1u}) - LO_1$	182	187	165	178 (178)	180 ^g
$\Gamma_4^-(T_{1u}) - LO_2$	472	461	451	478 (469)	468 ^g
$\Gamma_4^-(T_{1u}) - LO_3$	677	698	647	697 (696)	717 ^g

^a Frequencies calculated by the PBE0 functional with a reduced level (XLGRID) of DFT integration accuracy are given in brackets

^b [919]

^c [920]

^d [921]

^e [922]

^f [890]

^g [923]

constant a , the band gap E_{gap} and the high-frequency dielectric constant ϵ_{∞} . The numerical values of Born charges in BaTiO₃ agree satisfactory with the experimental estimates [890] for all the presented XC functionals. In spite of the presumable basis set dependence of Mulliken charges, the difference between the PBE0 charges from [882] and from [883] is of the same order (about 0.1 e) as that due to use of different XC. The phonon frequencies obtained for the cubic phase in other computations were considered in [882], where the advantage of the PBE0 functional was established. The structural instability of the cubic BTO due to soft modes was obtained by all XC functionals considered (see Table 9.34). The data from Table 9.34 show that the LCAO LDA calculation, while underestimating the cell constant of the cubic BTO, produces phonon frequencies with approximately the same deviation from experimental values as the PBE0 functional. In the case of the PBE0 XC functional the calculations using lower precision on DFT integration (the corresponding results are given in parenthesis) show that the decrease of the

Table 9.35 Calculated bulk properties of the tetragonal, orthorhombic and rhombohedral phases of BaTiO₃. Fractional displacements x_A, y_A, z_A of the atom A are given in respect to the ideal cubic location (see Table 9.36 for the parameterization of Wyckoff positions); the total energy, ΔE_0 , is calculated relative to the cubic phase; ϵ_∞ —high-frequency dielectric constant

Phase, Property	This work			Other theoretical results		Experiment ^c
	LDA	PBE	PBE0	LDA ^a	PBE ^b	
Tetragonal, SG 99						
Cell a (Å)	3.952	4.007	3.968	3.994	3.976	3.997
c (Å)	3.987	4.186	4.137	4.036	4.172	4.031
z_{Ti}	0.0115	0.0193	0.0203	0.0143	0.0188	0.0203
z_{bO}	−0.0168	−0.0436	−0.0431	−0.0307	−0.0473	−0.0258
z_{cO}	−0.0107	−0.0246	−0.0226	−0.0186	−0.0266	0.0123
Bulk modulus, B (GPa)	160	100	112		82.9	141 ^d , 134 ^e
Cohesive energy, E_{at} (eV)	38.45	32.75	30.81		40.25	
Band gap, E_{gap} (eV)	2.0	1.9	4.1	2.3	1.6	3.4 ^f
ϵ_{∞} xx	6.20	5.86	4.77			5.19
zz	5.81	4.89	4.27			5.05 ^g
Total energy, ΔE_0 (eV)	−0.004	−0.046	−0.041		−0.045	
Orthorhombic, SG 38						
Cell a (Å)	3.951	3.995	3.958	3.984	3.991	3.983
b (Å)	5.614	5.792	5.728	5.674	5.783	5.674
c (Å)	5.623	5.837	5.770	5.692	5.822	5.692
z_{Ti}	0.0093	0.0172	0.0175	0.0127	0.0159	0.0170
z_{aO}	−0.0085	−0.0203	−0.0186	−0.0144	−0.0206	−0.0110
y_{cO}	−0.0078	−0.0154	−0.0139	−0.0230	−0.0159	−0.0096
z_{eO}	−0.0130	−0.0314	−0.0307	−0.0162	−0.0309	−0.0218
Bulk modulus, B (GPa)	154	96	109		87.4	
Cohesive energy, E_{at} (eV)	38.46	32.76	30.82		40.26	
Band gap, E_{gap} (eV)	2.1	2.5	4.7			
ϵ_{∞} xx	6.17	5.69	4.69			
yy	6.02	5.34	4.59			
zz	5.82	4.81	4.16			
Total energy, ΔE_0 (eV)	−0.005	−0.058	−0.056		−0.060	
Rhombohedral, SG 160						
Cell a (Å)	3.966	4.073	4.029	4.001	4.073	4.004
α (deg)	89.958	89.710	89.727	89.87	89.74	89.8
z_{Ti}	−0.0080	−0.0150	−0.0151	−0.011	−0.0150	−0.0128
x_{O}	0.0069	0.0143	0.0129	0.0133	0.0141	0.0109
z_{O}	0.0109	0.0249	0.0242	0.0192	0.0245	0.0193
Bulk modulus, B (GPa)	153	101	114		94.6	
Cohesive energy, E_{at} (eV)	38.46	32.77	30.83	38.27	40.26	
Band gap, E_{gap} (eV)	2.2	2.7	4.9	2.3		
ϵ_{∞} xx	6.05	5.42	4.62			6.19

(continued)

Table 9.35 (continued)

Phase, Property	This work			Other theoretical results		Experiment ^c
	LDA	PBE	PBE0	LDA ^a	PBE ^b	
zz	5.82	4.80	4.13			5.88 ^h
Total energy, ΔE_0 (eV)	−0.005	−0.061	−0.061	−0.04	−0.060	

^a [894]
^b [891]
^c Experimental lattice parameters and atomic positions [916]
^d [917]
^e Calculated from elastic constants obtained in [918]
^f [921]
^g Taken from [895]
^h [901]

integration accuracy level can lead to errors in phonon frequencies of the order of 10 cm^{−1}. The three BTO ferroelectric phases were treated by the same DFT method in [865, 891]. However, these two works considered mainly the structural properties of the ferroelectric phases. In Table 9.35 we compare the results from [883] using the various XC functionals, other theoretical values, [865, 891] and experimental data available for the crystals considered. Unexpectedly, LDA on average gives good agreement with the experimental structural data for the BaTiO₃ phases. Moreover, in spite of the length of the lattice vectors being underestimated, LDA produces atomic positions in the cell that are of the same quality as those produced by PBE0. On the other hand, as expected, both LDA and PBE XC functionals substantially underestimate the band gap and, as a rule, overestimate the components of the high-frequency dielectric tensor. On the contrary, PBE0 slightly overestimates the band gap and underestimates the high-frequency dielectric constant. The main failure of the LDA method is its inability to reproduce the correct value of the cohesive energy of metal oxides (it is well known that LDA usually overestimates the cohesive energy of solids), whereas the PBE0 method gives good results for this quantity. Moreover, LDA seems to be unable to predict the correct sequence of the total electronic energies for the phases considered. No definite conclusions for the calculated bulk moduli can be made because of a lack of sufficiently precise experimental data.

Crystalline phonon mode symmetry is defined by the corresponding space group irreducible representations (IR) induced from the IR occupied by the atom site-symmetry group corresponding to the atomic coordinates (x, y, z) [892, 1145]. Table 9.36 gives the symmetry of phonons in four BTO structures: paraelectric cubic and three ferroelectric ones (tetragonal, orthorhombic, rhombohedral), see Fig. 9.12. The phase transitions in BTO are connected with the soft mode in the Γ point of BZ, that is, they take place without an increase in the five atom primitive cell [892]. Therefore the total number of optical TO modes is 12. In the footnote to Table 9.36 we give the symmetry of optical IR, Raman, silent and acoustic modes, using the conventional space group IR labels [17]. In the Γ point

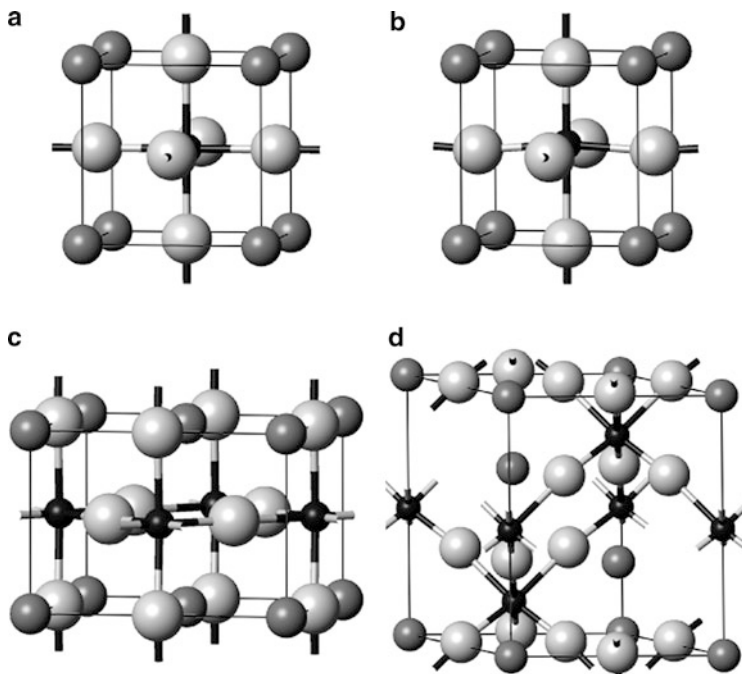


Fig. 9.12 The structure of the conventional unit cells for (a) cubic, (b) tetragonal, (c) orthorhombic, and (d) rhombohedral BaTiO_3 . Legend: Ti—small balls, Ba—middle balls, O—large balls

of BZ there is a one-to-one correspondence between these labels and those used for the corresponding point-symmetry groups of a crystal. This correspondence is given in the footnote to Table 9.36 and used in Tables 9.37, 9.38, 9.39 giving the calculated phonon frequencies. In the cubic perovskite structure (Fig. 9.12a) Ba and Ti atoms occupy the Wyckoff positions a and b with the site-symmetry group O_h and three oxygen atoms occupy the Wyckoff position c with the site-symmetry D_{4h} . It is seen from Table 9.36 that the IR active Γ_{4-} (T_{1u}) modes are induced by all the five atoms coordinates, but the silent Γ_{5-} (T_{2u}) mode-only by three oxygen coordinates. In the ferroelectric phases the site-symmetry groups of Ti and Ba atoms are C_{4v} , C_{2v} and C_{3v} , for tetragonal (Fig. 9.12b), orthorhombic (Fig. 9.12c) and rhombohedral (Fig. 9.12d) structures, respectively. The Wyckoff position c occupied by three oxygen atoms in the cubic phase is split into two nonequivalent sets in tetragonal and orthorhombic phases with the site-symmetry (C_{4v} , C_{2v}) and (C_{2v} , C_s), respectively. Finally, in the rhombohedral phase all the three oxygens are equivalent to the site-symmetry group C_s . The information collected in Table 9.36 is useful for the analysis of the role of different atoms displacements in vibrational modes of different symmetry. For example, in the orthorhombic phase silent modes are absent, but in the other three phases these modes are connected with the displacements of oxygen atoms only. Using the induced IR of space groups [13] allows one to extend

Table 9.36 Wyckoff positions of atoms (in reduced coordinates of primitive cells), site symmetry, phonon symmetry^a, and IR indexes^b for the cubic and ferroelectric phases of BaTiO₃. For space groups (SG) Schönflis symbols, international symbols and numbers have been given

Cubic phase ($T > 393$ K)	Tetragonal phase ($T = 396$ – 278 K)	Orthorhombic phase ($T = 278$ – 183 K)	Rhombohedral phase ($T < 183$ K)
$O_{1h}(Pm\bar{3}m), SG 221$	$C_{4v}^1(P4mm), SG 99$	$C_{2v}^{14}(Amm2), SG 38$	$C_{3v}^5(R3m), SG 160$
Ba: 1a	Ba: 1a	Ba: 1a	Ba: 1a
(0, 0, 0)	(0, 0, 0)	(0, 0, 0)	(0, 0, 0)
O_h	C_{4v}	C_{2v}	C_{3v}
$T_{1u}(x, y, z) \rightarrow \Gamma_{4-}$	$A_1(z) \rightarrow \Gamma_1$ $E(x, y) \rightarrow \Gamma_5$	$A_1(z) \rightarrow \Gamma_1$ $B_1(x), B_2(y) \rightarrow \Gamma_3, \Gamma_4$	$A_1(z) \rightarrow \Gamma_1$ $E(x, y) \rightarrow \Gamma_3$
Ti: 1b	Ti: 1b	Ti: 1b	Ti: 1a
$(\frac{1}{2}, \frac{1}{2}, \frac{1}{2})$	$(\frac{1}{2}, \frac{1}{2}, \frac{1}{2} + z_{Ti})$	$(\frac{1}{2}, \frac{1}{2} + z_{Ti}, \frac{1}{2} + z_{Ti})$	$(\frac{1}{2} + z_{Ti}, \frac{1}{2} + z_{Ti}, \frac{1}{2} + z_{Ti})$
O_h	C_{4v}	C_{2v}	C_{3v}
$T_{1u}(x, y, z) \rightarrow \Gamma_{4-}$	$A_1(z) \rightarrow \Gamma_1$ $E(x, y) \rightarrow \Gamma_5$	$A_1(z) \rightarrow \Gamma_1$ $B_1(x), B_2(y) \rightarrow \Gamma_3, \Gamma_4$	$A_1(z) \rightarrow \Gamma_1$ $E(x, y) \rightarrow \Gamma_3$
O: 3c	O⁽¹⁾: 1b	O⁽¹⁾: 1a	O: 3b
$(\frac{1}{2}, \frac{1}{2}, 0)$	$(\frac{1}{2}, \frac{1}{2}, z_{bO})$	$(0, \frac{1}{2} + z_{aO}, \frac{1}{2} + z_{aO})$	$(\frac{1}{2} + x_O, \frac{1}{2} + x_O, z_O)$
D_{4h}	C_{4v}	C_{2v}	C_{3v}
$A_{2u}(z) \rightarrow \Gamma_{4-}$	$A_1(z) \rightarrow \Gamma_1$	$A_1(z) \rightarrow \Gamma_1$	$A''(z) \rightarrow \Gamma_2, \Gamma_3$
$E(x, y) \rightarrow \Gamma_{5-}$	$E(x, y) \rightarrow \Gamma_5$	$B_1(x), B_2(y) \rightarrow \Gamma_3, \Gamma_4$	$A'(x) \rightarrow \Gamma_1, \Gamma_3$ $A'(y) \rightarrow \Gamma_1, \Gamma_3$
	O⁽²⁾: 2c	O⁽²⁾: 2e	-
	$(\frac{1}{2}, 0, \frac{1}{2} + z_{cO})$	$(\frac{1}{2}, \frac{1}{2} + y_{eO}, z_{eO})$	
	C_{2v}	C_s	
	$A_1(z) \rightarrow \Gamma_1, \Gamma_2$ $B_1(x) \rightarrow \Gamma_5$ $B_2(y) \rightarrow \Gamma_5$	$A''(z) \rightarrow \Gamma_2, \Gamma_3$ $A'(x) \rightarrow \Gamma_1, \Gamma_4$ $A'(y) \rightarrow \Gamma_1, \Gamma_4$	

^a Phonon spectra constituents:

SG 221: $4\Gamma_{4-} + \Gamma_{5-}$; **acoustic** Γ_{4-} ; **IR** $3\Gamma_{4-}$; **silent** Γ_{5-} .

SG 99: $4\Gamma_1 + \Gamma_2 + 5\Gamma_5$; **acoustic** $\Gamma_1 + \Gamma_5$; **Raman** $3\Gamma_1 + 4\Gamma_5$; **IR** $3\Gamma_1 + 4\Gamma_5$; **silent** Γ_2 .

SG 38: $5\Gamma_1 + \Gamma_2 + 4\Gamma_3 + 5\Gamma_4$; **acoustic** $\Gamma_1 + \Gamma_3 + \Gamma_4$; **Raman** $4\Gamma_1 + \Gamma_2 + 3\Gamma_3 + 4\Gamma_4$;

IR $4\Gamma_1 + 3\Gamma_3 + 4\Gamma_4$; **IR** $4\Gamma_1 + 3\Gamma_3 + 4\Gamma_4$.

SG 160: $4\Gamma_1 + \Gamma_2 + 5\Gamma_3$; **acoustic** $\Gamma_1 + \Gamma_3$; **Raman** $3\Gamma_1 + 4\Gamma_3$; **IR** $3\Gamma_1 + 4\Gamma_3$; **silent** Γ_2 .

^b Phonon mode symbols accepted in literature: **SG 221:** $\Gamma_{4-} - T_{1u}, \Gamma_{5-} - T_{2u}$;

SG 99: $\Gamma_1 - A_1$; **SG 221:** $\Gamma_2 - B_1, \Gamma_5 - E$; **SG 38:** $\Gamma_1 - A_1, \Gamma_2 - A_2, \Gamma_3 - B_1, \Gamma_4 - B_2$;

SG 160 $\Gamma_1 - A_1, \Gamma_2 - A_2, \Gamma_3 - E$.

Table 9.36 to the other symmetry points of BZ for a detailed interpretation of the vibrational spectra, found in the neutron-scattering experiments. To the best of our knowledge, the comparative phonon symmetry analysis in BTO four phases is given in [883] for the first time.

In Tables 9.37, 9.38, 9.39 we give the symmetry and calculated phonon frequencies for all the three ferroelectric BTO phases. We compare the results of the calculations [883] both with any other theoretical values and with the existing experimental data for the tetragonal and rhombohedral phases. For the orthorhombic

Table 9.37 Calculated and experimental Γ -point phonon frequencies (cm^{-1}) for the tetragonal phase of BaTiO_3 (the sequence number is given before the symbol for multiple modes)

Mode	This work			Experiment		Other theoretical results		
	LDA	PBE	PBE0	[898]	[899]	[895]	[896]	[897]
TO								
1E	79i	138i	139i	soft		161i	122i	148i
1A ₁	190	159	173	170	280	161	152	171
2E	192	171	185	180	190	167	163	177
B ₁ (<i>silent</i>)	301	282	301	305	303	287	275	291
3E	302	298	320	305	280	284	290	288
2A ₁	237	362	384	270		302	363	323
4E	487	462	484	486	516	457	451	475
3A ₁	507	563	591	520		507	562	544
LO								
1E	188	165	178	180	140	162	–	–
1A ₁	195	191	205	185		180	–	–
2E	302	297	318	305	303	284	–	–
3E	462	446	474	463	640	444	–	–
2A ₁	465	460	489	475		452	–	–
4E	701	660	707	715	720	641	–	–
3A ₁	721	738	792	720		705	–	–

phase the experimental data are sparse, the other theoretical data are absent. To discuss the influence of the exchange-correlation (XC) potential on the calculated phonon frequencies, we give the results for LDA, GGA (PBE) and hybrid PBE0 XC potentials. In agreement with the experimental data (the low-temperature phase is rhombohedral) we obtained the structural instability via soft modes (imaginary frequencies) for the BTO tetragonal and orthorhombic phases and all the three XC potentials, see Tables 9.37, 9.38. No imaginary frequencies were obtained for the rhombohedral phase (see Table 9.39) which is stable at low temperatures. The calculated frequencies agree well with the experimental data. The accordance between the LDA frequencies and the experimental values is also sufficiently good, apparently due to the use of observed values for the lattice parameters and/or cell volume.

The approach used for BaTiO_3 (LCAO calculations with the PBE0 hybrid XC functional) seems to be efficient for the theoretical predictions of phase transitions in the crystalline systems poorly studied experimentally. In the next subsection it is shown that the use of the first-principles method allows the calculation of BaTiO_3 thermodynamic properties, which provides a valuable information on the low-temperature behavior that could not be easily obtained by experimental techniques.

Table 9.38 Calculated and experimental Γ -point phonon frequencies (cm^{-1}) for orthorhombic phase of BaTiO_3 (sequence number is given before symbol for multiple modes)

Mode	This work			Experiment [900]
	LDA	PBE	PBE0	
TO				
$1B_1$	61i	78i	66i	
$1B_2$	165	162	177	
$1A_1$	191	165	179	
$2B_1$	192	169	184	193
$2B_2$	191	276	297	270
$3B_2$	298	300	308	
A_2	301	294	317	320
$2A_1$	211	299	319	
$3A_1$	305	333	356	
$3B_1$	486	458	482	490
$4B_2$	490	483	500	
$4A_1$	506	550	578	532
LO				
$1B_1$	188	165	178	
$1B_2$	191	180	193	
$1A_1$	191	269	284	
$2B_2$	298	277	299	
$2A_1$	214	299	319	320
$3A_1$	305	371	375	
$3B_2$	459	438	465	
$2B_1$	461	440	469	
$4A_1$	506	579	610	
$3B_1$	701	666	711	
$4B_2$	716	717	765	720

9.3.5 First-Principles Calculations of the Thermodynamic Properties of BaTiO_3 of Rhombohedral Phase

The stable structure of BTO below 183 K is rhombohedral. The number of calculations performed for this phase is noticeably smaller than for the cubic phase. The phonon spectra in the rhombohedral BTO have been calculated in several works [893, 895, 902, 903]. The Born effective charges, dielectric tensors and dynamical matrices (yielding phonon frequencies) in the rhombohedral BTO were obtained for the first time in [893] using a variational approach to the density-functional perturbation theory (DFPT). In the work [902] the methods of DFPT were further improved and used to calculate various physical linear-response properties for rhombohedral BTO. The resulted phonon frequencies are close to those found in [893]. Calculations of the phonon density of states, dispersion relations and the electromechanical response of the BTO were reported also in [903]. The nonlinear

Table 9.39 Calculated and experimental Γ -point phonon frequencies (cm^{-1}) for rhombohedral phase of BaTiO_3 (sequence number is given before symbol for multiple modes)

Mode	This work			Experiment [924]	Other theoretical results			
	LDA	PBE	PBE0		[895]	[902]	[903]	
TO								
1E	145	165	180	173	163	164	162	
1A ₁	191	167	181		167	169	167	
2E	191	264	264		210	206	240	
A ₂ (silent)	297	279	301		277	278	274	
3E	306	299	319	242	293	293	296	
2A ₁	200	309	332		259	255	295	
4E	489	474	493		470	472	468	
3A ₁	508	544	571		512	511	527	
LO								
1E	190	176	190	187	174	175	176	
1A ₁	193	182	197		178	179	183	
2E	306	299	319		310	293	293	296
3E	460	441	468		441	443	440	
2A ₁	471	467	498	485	461	460	462	
3A ₁	707	689	739	714	676	677	679	
4E	713	705	750		687	687	688	

optical susceptibilities and Raman scattering spectra of the ferroelectric phases of the BTO were computed [895] using a first-principles approach based on DFPT. The close relationship between ferroelectricity and BTO lattice dynamics is well known [904]. Infrared spectra, Raman or neutron scattering are valuable techniques for the study of BTO lattice dynamics experimentally. One of the ways to predict theoretically thermal and vibrational effects is the Debye model, [905] which is based on an energy-volume relationship in the static approximations. Such approach has been applied to atomistic study of thermal properties of some perovskites [877, 906–908] including the cubic phase of BTO [906].

However, the temperature dependence of thermodynamic functions is governed by the details of vibrations of the atoms in system under consideration which are not considered within the Debye model. By this reason, the exact knowledge of the vibrational states of a solid is the key to the study of its thermodynamic properties as a function of temperature. As it follows from the above mentioned papers, the first-principles quantum-mechanical methods can be directly used for calculation of the phonon frequencies in crystal. Once the electronic (ground) state of a stable system of nuclei and electrons is found and the phonon (harmonic) frequencies are calculated, the free-energy temperature dependence can be analyzed to study the thermodynamic properties. Such approach corresponds to so-called quasi-harmonic approximation [860, 909] in which harmonically defined force constants calculated at fixed cell volume are combined with an anharmonic electronic potential. From the free vibrational energy the free enthalpy (or Gibbs energy) is reached relatively simply, giving the possibility of ab initio thermodynamic modeling on the crystals.

This technique has been applied to only few perovskite-type crystals: MgSiO_3 [910, 911] and CaIrO_3 [912]. The *ab initio* lattice-dynamical studies of BTO phases are mostly limited to zone-center modes. The quasiharmonic approximation to estimate the heat capacity and the thermal volume expansion of the stable rhombohedral BTO phase from the first principles has been applied in [913]. It should be noted that the calculation of thermal free energy of cubic, tetragonal and orthorhombic BTO phases requires treating the soft modes beyond the scope of quasiharmonic approximation, [860, 909] and cannot be done so easy as for the low-temperature stable phases. Thus, statistical-mechanic approaches based on effective Hamiltonian have been developed in several works [861–863, 914]. An effective Hamiltonian constructed from the results of LDA or GGA calculations was then used in Monte Carlo or molecular dynamics simulations of BTO for taking into account the anharmonic effects and predicting the phase transitions [862, 863].

Helmholtz energy per crystal unit cell consists of several terms, [909]

$$A(V, T) = E_{\text{el}}(V) + A_{\text{ph}}(V, T) + \Delta A_{\text{el}}(V, T) + A_{\text{conf}}(T) + A_{\text{ah}}(V, T) \quad (9.100)$$

The temperature-independent electronic total energy E_{el} (this energy formally corresponds to the Born–Oppenheimer potential energy at $T = 0$ K) can be obtained in first-principles calculations (via optimization at a fixed cell volume). The term A_{ph} is the free harmonic vibrational energy given by the well-known equation [902]:

$$A_{\text{ph}}(V, T) = \frac{1}{N} \left\{ \frac{1}{2} \sum_{\mathbf{k}} \sum_n \hbar \omega_n(\mathbf{k}, V) + k_B T \sum_{\mathbf{k}} \sum_n \ln [1 - \exp(-\hbar \omega_n(\mathbf{k}, V)/k_B T)] \right\} \quad (9.101)$$

where $\omega_n(V, \mathbf{k})$ —the phonon n th branch frequency at the point $\mathbf{k}$ calculated at the volume V ; $\hbar$ and k_B —Dirac and Boltzmann constants, respectively. The summation in Eq. (9.101) is done over all N points in the corresponding first Brillouin zone (BZ) and over all phonon branches, with regard to degeneracy. It should be pointed out that in the quasiharmonic approximation one can neglect the nonanalytical term of the dynamical matrices which comes from the coupling of the LO modes with the long-range dipolar Coulomb field. This term, which is the origin of the LO/TO splitting, will only affect the LO modes in a small portion of the BZ centered at Γ . Since the thermodynamic properties such as entropy, internal energy, and specific heat are obtained by summation (integration) within the full BZ, the contribution of LO modes can be ignored when $N \rightarrow \infty$.

The free electronic energy based on electronic excitations, ΔA_{el} , can be omitted from Eq. (9.100) at low temperatures for systems with a sufficiently large electronic band gap (in our case $E_{\text{gap}} = 4.9$ eV). The configurational term A_{conf} is volume-independent and it makes sense in the case of nonstoichiometric or defective crystals and for systems with statistical occupations, otherwise it can be also set to zero. The contribution of the anharmonic effects, A_{ah} , can, in principle, be treated by recently proposed method, developed within the analytical framework of the quasiharmonic

equation of state, taking into account the double-well energy displacements, [915] or by Monte Carlo [862] and molecular dynamic [863] simulations. However, when the system is far enough from the melting point and does not have “soft modes,” the anharmonic effects can be ignored to a very good approximation, since the inclusion of the actual electronic potential in the quasiharmonic approach implicitly takes into account a significant part of the anharmonic contributions. It was shown [860] that the vibrational energies obtained at constant volumes can simply be added to the electronic energy,

$$A(V, T) = E_{\text{el}}(V) + A_{\text{ph}}(V, T) \quad (9.102)$$

giving a very good approximation for the Helmholtz energy.

As the first term in Eq. (9.102) does not depend on the temperature, only the harmonic energy contributes to the heat capacity at constant volume:

$$C_V = \left(-T \frac{\partial^2 A_{\text{ph}}}{\partial T^2} \right)_V = \frac{k_B}{N} \sum_{\mathbf{k}} \sum_n \left[\frac{\hbar \omega_n(V, \mathbf{k})}{k_B T} \right]^2 \frac{\exp(\hbar \omega_n(V, \mathbf{k})/k_B T)}{[\exp(\hbar \omega_n(V, \mathbf{k})/k_B T) - 1]^2} \quad (9.103)$$

It should be noted that the heat capacity at constant pressure, C_P , is related to the heat capacity at constant volume, C_V , by the known [909] relationship $C_P - C_V = \alpha_V^2 B V T$, where $\alpha_V = (1/V) (\partial V / \partial T)_P$ is the volume thermal expansion coefficient, and B is the isothermal bulk modulus. For isolators at room temperature and below, the difference between C_P and C_V is small ($\leq 0.1 \text{ J mol}^{-1} \text{ K}^{-1}$) and is neglected in our further analysis.

Within the chosen approach, the total electronic energies of solids are obtained at constant volume of the unit cell, and for this reason the desired pressure-dependent Gibbs energy, $G(P, T)$ can be calculated basing on the volume-dependent Helmholtz energy, $A(V, T)$, via the well-known thermodynamic relation: $G(P, T) = A(V(P, T), T) + P V(P, T)$. The volume V in the right-hand side of this equation is considered to be the function of the pressure P and the temperature T . The pressure-volume equation of state (EOS) can be obtained from the negative change in the Helmholtz energy with respect to the volume: $P(V, T) = -(\partial A / \partial V)_T$. For this purpose the Helmholtz energy has to be calculated at different volumes for several fixed temperatures T_i , and the resulting values are fitted by any simplified form of EOS $A_i = A_i(V)$ for each respective temperature T_i . The calculated Helmholtz free energy versus volume is most frequently fitted by an isothermal third- or fourth-order finite strain EOS. The fourth-order Birch–Murnaghan EOS was used in [913]:

$$A(V, T) = A_0 + (9/2) B_0 V_0 f^2 \left\{ 1 + (B'_0 - 4) f + (3/4) [B_0 B''_0 + B'_0 (B'_0 - 7) + 143/9] f^2 \right\} \quad (9.104)$$

where $f = (1/2)[(V_0/V)^{2/3} - 1]$ is the Eulerian strain, B_0 , B'_0 , and B''_0 are the isothermal bulk modulus, its first and second pressure derivatives, correspondingly.

All the quantities with the subscript 0 correspond to zero pressure and are the functions of the temperature T . The dependence $V_0(T)$ can be used to obtain the thermal expansion coefficient $\alpha_V = (1/V_0) (\partial V_0/\partial T)_{P=0}$ at zero pressure.

The calculated rhombohedral BTO bulk properties are given in Table 9.40 where they are compared with the available theoretical [865, 891, 895, 902, 903] and experimental [916, 920, 921] data. It should be noted that almost all the previous computations (except [891]) were done within LDA at fixed (observed) lattice parameters or with a constrained experimental cell volume. This is the reason for the good agreement between the calculated and experimental atomic displacements. The PBE0 calculations [913] produce practically the same quality of BTO physical properties. Moreover, the deviations of the optimized lattice constant a and the angle α from the experimental values are less than 1% and 0.1%, correspondingly. Also, the values in Table 9.40 show that the hybrid PBE0 method provides a noticeable improvement compared to the plain PBE GGA approach. As expected and in accordance with the experimental observation, the structural instability via soft modes (imaginary frequencies) for the rhombohedral BTO is not observed at all cell volumes considered (see below). The zone-center phonon frequencies calculated with the totally (statically) optimized lattice parameters and atomic displacements are given in Table 9.41. For comparison, the previous theoretical LDA DFPT values and the available experimental data [924] are also given. The agreement between the LDA frequencies and experimental values is sufficiently good again owing to the use of the experimental values for the lattice parameters and/or cell volume. On average, the PBE0 results are as good as the LDA values in spite of the nonuse of any experimental information.

Strictly speaking, with the frozen phonon method used in [913] one can calculate the Fourier transformed force constant at $\mathbf{k} = \mathbf{0}$ only, but with a suitably chosen supercell one can obtain the BZ folded modes corresponding to the other points at the BZ. Upon the cell enlarging, the Γ -point of the reduced BZ accommodates $N - 1$ extra $\mathbf{k}$ -points from the first BZ, where N is the number of primitive cells in the supercell [1145]. Such an approach, however, requires an additional study of the convergence of the calculated properties when the supercell is increased. The main question is to what extent the calculated properties converge with the supercell-size increase. This question was addressed in [913] by calculating the vibrational contributions to the Helmholtz energy and heat capacity with supercells containing 8, 16 and 27 primitive rhombohedral cells. It should be noted that the vibrational contributions in Eqs. (9.101) and (9.103) need to be multiplied by the factor $Nn_A/(Nn_A - 1)$, where n_A is the number of atoms in the primitive unit cell. This factor takes into account the finite size of the cyclic crystal model represented by a supercell consisting of N primitive cells; it provides the correct total number of the vibrational states per primitive unit cell and ensures the true limiting behavior of the thermal contributions at $T \rightarrow \infty$.

Figure 9.13 shows the temperature dependence of the thermal contribution to the Helmholtz energy calculated by Eq. (9.101) using different supercells with the primitive cell volume $V^* = 65.40 \text{ \AA}^3$. This volume was obtained by minimizing $E_{\text{cl}}(V)$ statically, and it corresponds to the optimized lattice parameters

Table 9.40 Calculated bulk properties of the rhombohedral phase of BaTiO₃. The fractional displacements $x_A, y_A, \text{and } z_A$ of atom A are given in respect to the ideal cubic location (**Ba: 1a** (0, 0, 0); **Ti: 1a** (0.5 + x_{Ti} , 0.5 + x_{Ti} , 0.5 + x_{Ti}); **O: 3b** (0.5 + x_O , 0.5 + x_O , 0.5 + x_O)); the total energy, ΔE is calculated relative to the cubic phase (without thermal contributions)

Phase, Property	Other theoretical results						
	PBE0	LDA ^[865]	LDA ^[895]	LDA ^[902]	LDA ^[903]	PBE ^[891]	Experiment ^[924]
Cell							
a (Å)	4.029 (4.034 at $T = 0$ K, $P = 0$)	4.001	4.003	4.000	4.000	4.073	4.004
α (deg)	89.727 (89.715 at $T = 0$ K, $P = 0$)	89.87	89.84	89.85	89.90	89.74	89.8
x_{Ti}	−0.0151	−0.0110	−0.0105	−0.0108	−0.0133	−0.0150	−0.0128
x_O	0.0129	0.0133	0.0116	0.0123	0.0130	0.0141	0.0109
z_O	0.0242	0.0192	0.0183	0.0193	0.0200	0.0245	0.0193
Bulk modulus, B (GPa)	113.6 (111.6 at $T = 0$ K, $P = 0$)	−	−	−	−	94.6	−
Pressure derivative of bulk modulus B'	6.32 (5.91 at $T = 0$ K, $P = 0$)	−	−	−	−	40.26	−
Cohesive energy, E_{at} (eV)	30.83	38.27	−	−	−	−	(31.6 ^b)
Band gap, E_{gap} (eV)	4.9	2.3	−	−	−	−	(3.4 ^c)
Total energy, ΔE (eV)	−0.061	−0.046	−	−	−	−0.060	−

^a The optimization of atomic positions in LDA was performed at fixed lattice parameters or with the constrained experimental cell volume.

^b For cubic phase.^[920]

^c For tetragonal phase.^[921]

Table 9.41 Calculated and experimental Γ -point phonon frequencies (cm^{-1}) for a rhombohedral phase of BaTiO_3 (the sequence number is given before the symbol for multiple modes)

Mode	This work PBE0	Other theoretical results ^a				Experiment ^[924]
		LDA ^[893]	LDA ^[895]	LDA ^[902]	LDA ^[903]	
TO						
1E	180	161	163	164	162	
1A ₁	181	168	167	169	167	173
2E	264	205	210	206	240	
A ₂ (<i>silent</i>)	301	274	277	278	274	
3E	319	293	293	293	296	
2A ₁	332	265	259	255	295	242
4E	493	461	470	472	468	
3A ₁	571	505	512	511	527	522
LO						
1E	190	173	174	175	176	
1A ₁	197	180	178	179	183	187
2E	319	293	293	293	296	310
3E	468	438	441	443	440	
2A ₁	498	462	461	460	462	485
3A ₁	739	702	676	677	679	714
4E	750	725	687	687	688	

^a At experimental unit cell parameters or with a constrained experimental cell volume.

of the rhombohedral BTO given in Table 9.35. For comparison, the vibrational contributions were also calculated for the primitive ($1 \times 1 \times 1$) unit cell, which gives exact vibrational frequencies at the Brillouin-zone center only. As is seen in Fig. 9.13, the free energy at 200 K decreases from -3.7 to -5.0 kJ mol⁻¹ when one is going from a ($1 \times 1 \times 1$)—primitive—unit cell to a ($3 \times 3 \times 3$) supercell. The free-energy temperature dependences calculated for 16 and 27 primitive unit cells are practically indistinguishable, whereas 8 primitive unit cells are enough to give a good approximation for the ($3 \times 3 \times 3$) supercell curve.

In the calculations [913], a ($2 \times 2 \times 2$) supercell was used for the calculation of a volume and temperature dependences of Helmholtz energy. A set of 12 constant-volume structure optimizations at cell volumes in the range from 63.8 to 67.4 Å³ was performed. A full set of phonon frequencies has been obtained for each statically optimized structure. The volume dependence of zone-center frequencies is given in Fig. 9.14a, whereas in Fig. 9.14b, the volume dependence of acoustic frequencies at the L (0 0 1/2), FA (0 1/2 1/2), and T (1/2 1/2 1/2) points of BZ is shown. The mode Gruneisen parameters $\gamma_n = (V/\omega_n)\partial\omega_n/\partial V$ were estimated from the data represented in Fig. 9.14b, providing a useful insight into the thermal expansion mechanisms. The values of $\gamma_n = 4.1, 2.1, 1.7, 1.7$ were obtained for acoustic modes with distinguishable (rising) frequencies.

Helmholtz energy $A = A(V, T)$ was calculated at each considered volume over temperature range 0–250 K with 12.5 K step. With this dependence, it was possible to find the cell volume and free energy at $P = 0$ directly from the zero pressure

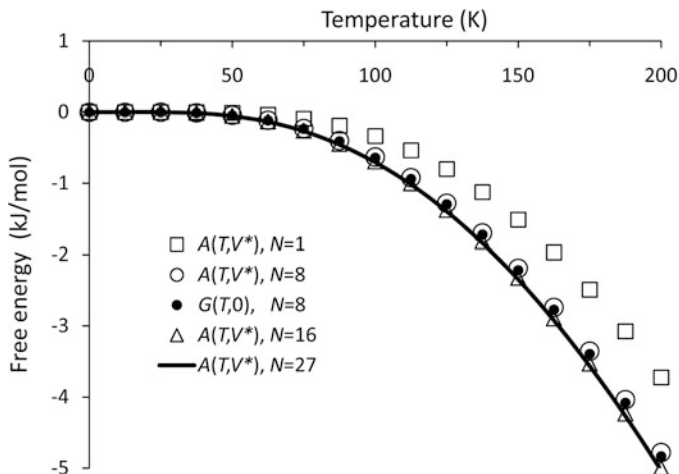


Fig. 9.13 Temperature dependence of the relative change in free energy, calculated using different supercells for the rhombohedral BaTiO₃

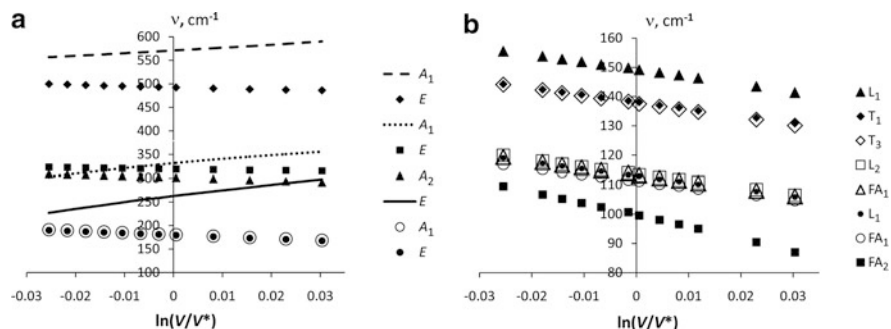
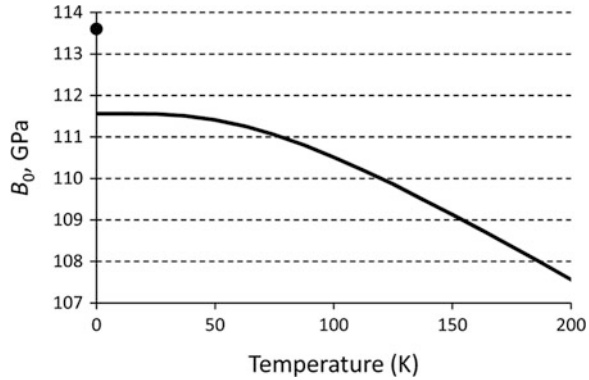


Fig. 9.14 Calculated volume dependence of selected phonon frequencies in BaTiO₃ rhombohedral phase. (a) Zone-center modes. (b) Acoustic modes in L (0 0 1/2), FA (0 1/2 1/2), and T (1/2 1/2 1/2) points of BZ

line, $-(\partial A/\partial V)_T = 0$. For this purpose, the 4th-order Birch–Murnaghan [925] EOS Eq. (9.104) was applied to $A_i = A_i(V, T_i)$ at every temperature T_i . As a result, the temperature dependences of equilibrium volume $V_0(T)$, the isothermal bulk modulus $B_0(T)$ and its pressure derivatives $B'_0(T)$, $B''_0(T)$, as well as $A_0(V_0, T)$ at $P = 0$ were obtained. The temperature dependence of the isothermal bulk modulus is shown in Fig. 9.15, whereas the values of B_0 and $B'_0(T)$, at $T = 0$ K, are inserted in Table 9.40 to compare them with the corresponding static results. The difference between the two sets of quantities is due to zero-point vibrations. The correction for the zero-point motion is a 0.3% increase in volume ($V^* = 65.40 \text{ \AA}^3$; $V_0(0) = 65.62 \text{ \AA}^3$) and a 2% decrease in the bulk modulus and its pressure derivative from their athermal values given by the static optimization. When the temperature rises

Fig. 9.15 Calculated temperature dependence of the isothermal bulk modulus for the BaTiO₃ rhombohedral phase. A static value is shown by a dot at $T = 0$ K



from 0 to 200 K, the bulk modulus reduces from 111.6 to 107.6 GPa (see Fig. 9.15). Consequently, the pressure dependences of the mentioned quantities can also be easily obtained, but this was not done in [913] because of the relatively narrow interval of the explicit volumes (and implicit pressures) considered in this study. Due to the well-known thermodynamic relation, $A_0(V_0(T), T)$ is equal to $G(0, T)$ at zero pressure. The resulting dependence of Gibbs energy on temperature is depicted in Fig. 9.12. As can be seen, $G(0, T)$ almost coincides with $A(V^*, T)$ calculated at $V = V^*$ using the same $2 \times 2 \times 2$ supercell. Supposedly, this is due to the fact that the volume-dependent trend of the vibrational energy at a constant temperature is weak in the vicinity of $V = V^*$, which results in reasonability of the straightforward harmonic approximation. One can expect that both quantities still remain close to each other for other stable perovskite crystalline phases at zero pressure and below the room temperatures. This can provide a considerable saving in computer time needed for estimation of thermal contributions to free energy, entropy, and heat capacity.

The calculated temperature dependence of the cell volume at $P = 0$ gives an opportunity to estimate the thermal expansion coefficient of the rhombohedral BTO. Fig. 9.16 shows the obtained results in the form $\eta(T)$, where $\eta = 10^4 \cdot (\tilde{a} - \tilde{a}_0)/\tilde{a}_0$, and $\tilde{a} = V^{1/3}$ is so-called pseudocubic lattice parameter. It is seen that this quantity tends to zero as T^2 or faster when $T \rightarrow 0$ K in a quasiharmonic approximation. Indeed, using the Debye approximation [926] for the internal energy together with the Gruneisen equation for the relative change in volume, [927] it can be shown that $\eta \propto T^4$ when $T \rightarrow 0$ K at $P = 0$.

The thermal expansion of the rhombohedral BTO has been investigated experimentally using the dilatometric technique [928, 929]. The experimental data are given in the form of linear (normal) thermal strain $\eta_{T_0}(T) = 10^4 \cdot [L(T) - L(T_r)]/L(T_r)$, where L is the length of the experimental species and T_r is some reference temperature (different in different experiments). In the temperature interval $T = 100$ –183 K, the experimenters reported the values of $3.4 \cdot 10^{-6} \text{K}^{-1}$ [928], $5.2 \cdot 10^{-6} \text{K}^{-1}$ [930], and $7.5 \cdot 10^{-6} \text{K}^{-1}$ [929] for the linear (isotropic)

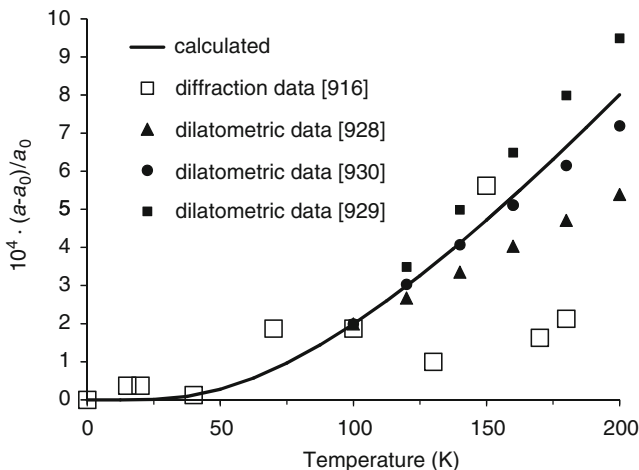


Fig. 9.16 Comparison of experimental and calculated results for the temperature dependence of the relative variation for the pseudocubic lattice parameter in the rhombohedral BaTiO_3

thermal expansion coefficient L . If we assume that the experimental temperature dependence of $L(T)$ can be expressed in a linear form using the reported values of α_L ,

$$\frac{L(T)}{L(100)} = 1 + \alpha_L(T - 100) \quad (9.105)$$

where $L(100)$ is proportional to $\tilde{a}$, one can compare the theoretical curve with the experimental estimates [928–930] recalculating them with the equation:

$$\eta(T) = 10^4 \left\{ \frac{\tilde{a}(100)}{\tilde{a}(0)} [1 + \alpha_L(T - 100)] - 1 \right\} \quad (9.106)$$

The calculated $\eta(T)$ qualitatively agrees with the experimentally estimated dependencies. As can be seen in Fig. 9.16, the agreement between the theoretical and measured [930] temperature dependence is almost fine, although a relatively large discrepancy between the available experimental results should be noted. Figure 9.16 demonstrates also the direct results for η calculated from the crystallographic data obtained by neutron-diffraction techniques [916]. In spite of the large scattering of these data, a good qualitative agreement with theoretical results is observed. The results obtained permit one to theoretically estimate the temperature dependence of the volume thermal expansion coefficient in the rhombohedral BTO. To perform a precise differentiation, one can adopt an analytical approximation of the η temperature dependence. It was found in [913] that an appropriate function can be chosen in the form of a linear combination of contributions, originating in the Einstein and Debye theories [926]:

Table 9.42 Coefficients in Eqs. (9.107)–(9.109) for the approximation of the calculated volume-temperature dependence in the rhombohedral BaTiO₃

Coefficient	Value ^[931]	Coefficient	Value
c_1	−0.07713	$d_1 \cdot 10^4$	17.175
c_2	0.02433	$d_2 \cdot 10^4$	53.495
c_3	0.30548	$d_3 \cdot 10^4$	−24.482
c_4	0.06513	θ_1, K	164.94
c_5	0.03487	θ_2, K	440.07
c_6	−0.00324	θ_3, K	684.20

$$\eta_V(T) = \frac{V}{V_0} - 1 = d_1 \frac{1}{\exp(\theta_1/T) - 1} + d_2 \frac{T}{\theta_2} D_r(\theta_2/T) + d_3 \ln[1 - \exp(-\theta_3/T)] \quad (9.107)$$

where $d_1, d_2, d_3, \theta_1, \theta_2$, and θ_3 are the empirical parameters and $D_r(x)$ is the rational approximation of the well-known Debye function $D(x)$ proposed in [931]:

$$D_r(x) = \frac{1 + c_1x + c_2x^2}{Q(x)}; \quad Q(x) = 1 + c_3x + c_4x^2 + c_5x^3 + c_6x^4 + c_2(5/\pi^4)x^5 \quad (9.108)$$

The parameters c_i determined in the original work [931] are given in Table 9.42. The representation Eq. (9.108) satisfies the true asymptotic at $x \rightarrow \infty$ and takes the correct value at $x = 0$. As a result, the empirical function Eq. (9.108) provides the correct limiting behavior of $\eta(T)$ at $T \rightarrow 0$, and it rises as T^1 at $T \rightarrow \infty$. The empirical coefficients $d_1, d_2, d_3, \theta_1, \theta_2$, and θ_3 were estimated (Table 9.42) by the least-squares fitting of the dependence of η on T . The standard deviation for the approximation Eq. (9.108) of η is $1.3 \cdot 10^{-7}$. A differentiation of Eq. (9.107) produces the following analytical temperature dependence of α_V :

$$\alpha_V = \frac{V_0}{V} \frac{\partial \eta_V}{\partial T} = \frac{V_0}{V} \left\{ d_1 \frac{\theta_1}{T^2} \frac{\exp(\theta_1/T)}{[\exp(\theta_1/T) - 1]^2} + d_2 \frac{1}{\theta_2} R(\theta_2/T) - d_3 \frac{\theta_3}{T^2} \frac{1}{\exp(\theta_3/T) - 1} \right\} \\ R(x) = \frac{1 - c_2x^2}{Q(x)} + \frac{xQ'(x)}{Q(x)} D_r(x) \quad (9.109)$$

In the interval from $T = 100$ – 183 K, the calculated values of α_V rise from $1.4 \cdot 10^{-5} \text{ K}^{-1}$ to $2.010 \cdot 10^{-5} \text{ K}^{-1}$. The relation $\alpha_L = \alpha_V/3$ provides the temperature dependence of the average linear (isotropic) thermal expansion coefficient α_L .

In Fig. 9.17a, the temperature dependence of this quantity with regard to Eq. (9.109) is shown. At $T = 100 \text{ K}$ and $T = 183 \text{ K}$, the calculated values of α_L are $4.610 \cdot 10^{-6} \text{ K}^{-1}$ and $6.910 \cdot 10^{-6} \text{ K}^{-1}$, respectively. So the agreement between the theoretical and experimental values of α_L can be considered satisfactory.

The thermal Gruneisen parameter, which is defined as $\gamma = \alpha_V B_0 V_0 / C_V^0$, is the weighted average of γ_n —the separate modes Gruneisen parameters [909, 926]. At low temperatures, the thermal Gruneisen parameter is determined mostly by low-

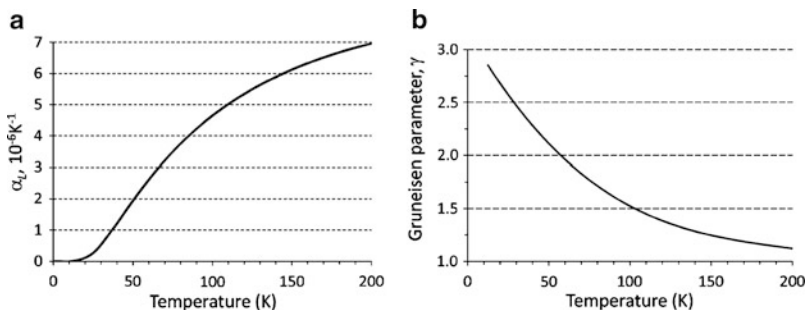


Fig. 9.17 (a) Calculated temperature dependence of the average linear (isotropic) thermal expansion coefficient for the rhombohedral BaTiO₃ at zero pressure. (b) Calculated temperature dependence of the thermal Gruneisen parameter

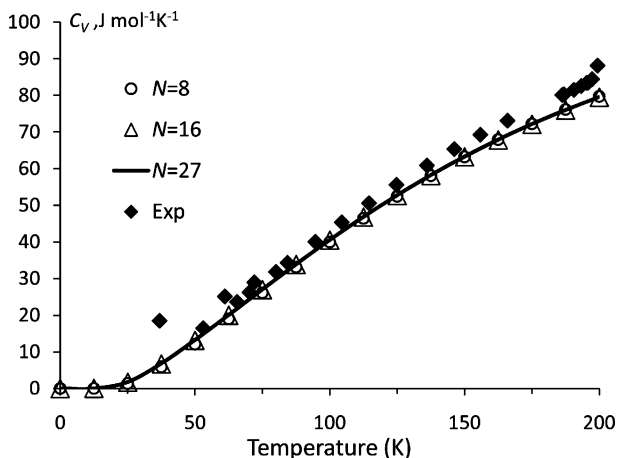


Fig. 9.18 Experimental [932] and theoretical temperature dependence of heat capacity, calculated in the harmonic approximation using different supercells for the rhombohedral BaTiO₃

frequency modes. All the quantities needed to calculate γ at zero pressure were obtained in [913]. The resulting temperature dependence of γ is given in Fig. 9.17b. It is clearly seen that the Gruneisen parameter decreases with temperature: it is about 3 near $T = 1$ K but tends to 1 as the temperature approaches to phase transition point. The relatively high value of γ at low temperatures is due to the dominant contribution of the lowest acoustic mode with $\gamma_n = 4.1$ (see Fig. 9.17b). The heat capacity temperature dependence $C_V^* = C_V(V^*, T)$ can be easily calculated at constant volume V^* using Eq. (9.103) and different supercells for the $\mathbf{k}$ -point summation (see Fig. 9.18). The knowledge of EOS permits one to calculate $C_V^0 = C_V(V_0, T)$, thus obtaining the correct temperature dependence at $P = 0$. For this purpose, the volume dependence of C_V at each considered temperature T_i was interpolated, using the fourth-order polynomial representation

on logarithmic strain $\epsilon = \ln(V/V^*)$. As in the case of free energy, the volume-temperature dependence (anharmonic effects) does not noticeably change C_V . The difference between C_V^* and C_V^0 for the $(2 \times 2 \times 2)$ supercell does not exceed $0.25 \text{ J mol}^{-1} \text{ K}^{-1}$, and these quantities cannot be distinguished in the scale of Fig. 9.18. Again, one can see that the results converge fast with the supercell size: supercells containing 8, 16, and 27 primitive cells produce close values of C_V^* . The agreement with the experimental data [932] for C_P is good, and the calculated curve lies close to the experimental line in the stability range of the BTO rhombohedral phase. The distinct peak on the experimental curve above the 183 K is attributed to the phase transition from the rhombohedral to the orthorhombic phase. The theoretical curve is smooth at all temperatures since it corresponds to a single phase.

Let us summarize the results of the calculations [913]. One can conclude that the parameter-free hybrid exchange-correlation PBE0 functional is able to predict correctly the structural stability, electronic properties, and phonon frequencies in a BaTiO_3 crystal. It is seen that the electronic energy and phonon frequencies calculated by first-principles methods can be used as input for the calculation of thermodynamic properties of low-temperature phases via a quasiharmonic approximation. This approach was used in [913] for obtaining the equation of state and estimating the bulk modulus, the equilibrium volume, the thermal volume expansion coefficient, and the heat capacity in the rhombohedral BaTiO_3 phase at zero pressure. The theoretical results obtained agree well with the available thermodynamic data. It has been found that the curvature of the volume dependence of the thermal contributions to the free energy and heat capacity is relatively flat in the vicinity of the equilibrium volume, and those quantities can be estimated at statically optimized lattice parameters and atomic positions via the harmonic approximation. This fact can provide a considerable saving in the computer time needed for the estimation of thermal contributions to free energy, entropy, and heat capacity. One can conclude that the use of the first-principles LCAO approach allows BaTiO_3 thermodynamic properties calculation, providing valuable information on the low-temperature behavior that is not easy to obtain by experimental techniques.

9.3.6 *Quantum Mechanics–Molecular Dynamics Approach to the Interpretation of X-Ray Absorption Spectra*

X-ray absorption spectroscopy (XAS) at synchrotron radiation sources is a modern structural tool providing the information on the local atomic and electronic structure around an atom of particular type. The size of the region probed by XAS depends on the degree of thermal and static disorder present in the compound and is typically about 3–10 Å around the absorbing atom. Even though a reliable theory of X-ray absorption spectra (EXAFS/XANES) was developed in the past [933], there is still a lack of accurate accounting for the disorder effects, in particular beyond the first coordination shell—in the region, where the so-called multiple-scattering

(MS) effects [933, 934] depending on many-atom distributions contribute. This problem strongly limits the conventional routine analysis and the interpretation of the EXAFS signals to the first coordination shell.

Currently the problem of disorder in EXAFS is theoretically considered within two approaches: one relies on the distribution of instantaneous interatomic distances contributing to the multiple-scattering paths [933], whereas the other uses the configurational averages of the EXAFS signals over n -atom distributions [935, 936].

Within the first approach, realized within the FEFF code [937], the treatment of the thermal and structural disorder is based on phenomenological models, such as the correlated Einstein and Debye models, Gaussian, or cumulant approximations [933]. However, few attempts have been made so far to use more rigorous approaches, based on semiempirical Hamiltonians and the *ab initio* density-functional method [938] or the equation-of-motion method [939].

In the second approach, implemented in the GNXAS code [936, 940], the configurational averages of the EXAFS signals are calculated using the low-order Taylor expansion for an amplitude and phase of the EXAFS signal and assuming small disorder.

In practice, an even better approach can be implemented using the FEFF or GNXAS code to generate a configuration-averaged EXAFS signal from a set of atomic configurations, which can be obtained from the molecular dynamics (MD), the Monte Carlo (MC), or the Reverse Monte Carlo (RMC) simulations [941–948]. Note that in the first two methods, MD and MC, the interaction between atoms is taken into account through the use of interatomic potentials, while in the RMC technique, no interatomic interactions are assumed.

An approach to the simulation of configuration-averaged X-ray absorption spectra, based on a combination of quantum mechanics and molecular dynamics (QM–MD) methods was proposed in [949–951]. The approach allows straightforward accounting for both thermal and structural disorder within the MS contributions. A proper application of *ab initio* quantum mechanics allows a number of empirical parameters used in the molecular dynamics simulation to be decreased, whereas the molecular dynamics allows one to account for the temperature effects. In all, the approach provides a way of accounting for the static and dynamic disorder in EXAFS signals from the coordination shells beyond the first one, where many-atom (multiple-scattering) effects are often important. This approach has been applied to the Ti K-edge EXAFS signal in a perovskite-type SrTiO_3 compound taken from [952], and to Re L_3 -edge EXAFS spectra in cubic ReO_3 , see [949, 950].

The scheme of the combined quantum mechanics–molecular dynamics (QM–MD) approach to the x-ray absorption spectra simulation is shown in Fig. 9.19.

It can be separated into several stages, which can be technically implemented in different ways.

One starts from the atomic structure of a compound, which should be obtained from a diffraction experiment or calculated by one of the *ab initio* quantum-chemistry codes, as, for example, the LCAO code [953] or the PW (plane wave) code [954]. One also obtains the information on the atomic charges. In LCAO

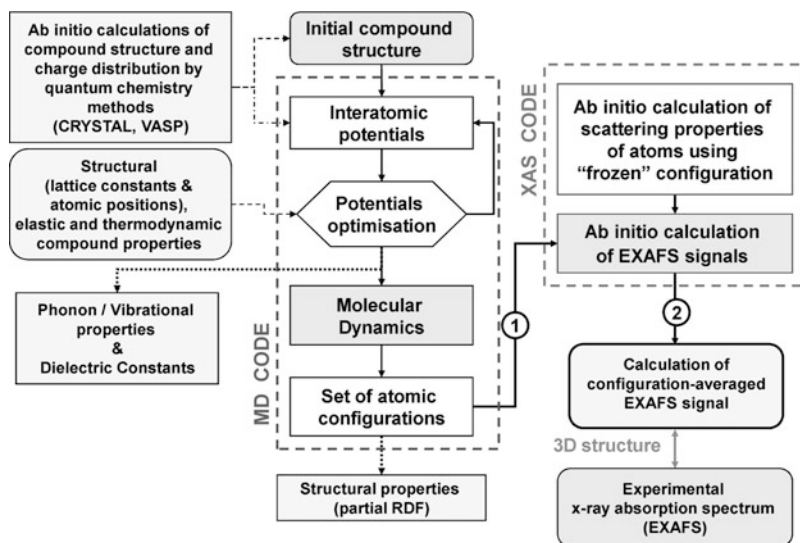


Fig. 9.19 Scheme of the combined quantum mechanics and molecular dynamics (QM-MD) approach to the x-ray absorption spectra simulation

calculations the atomic charges are found by Mulliken population analysis, whereas in PW calculations Bader atomic charges are used. The calculated atomic charges can be used for further empirical interatomic potential fitting; thus, the number of free unknown parameters is reduced. When the atomic structure of the compound is calculated, one needs to choose a set of interatomic potentials and perform their optimization by refining the potential parameters to some physical properties of the compound. These can be structural parameters (such as lattice constants and atomic fractional coordinates within the unit cell), elastic constants, and thermodynamic properties. To solve this problem, one can use the GULP code [955, 956], which incorporates the interatomic potentials optimization procedure. Note that the interatomic potentials thus obtained should allow an accurate reproduction of the structural parameters (normally to better than $\pm 0.01\text{--}0.02$ Å) to make a further comparison of the calculated and experimental EXAFS signals meaningful.

After a refinement of interatomic potentials, the vibrational frequencies, phonon dispersions, and density of vibrational states can be calculated and compared with the results of Raman scattering, infrared spectroscopy, or inelastic neutron scattering, when available.

At the next stage, the molecular dynamics simulation should be performed for the temperature of the EXAFS experiment. Note that when classical MD simulations are performed, as in the case of the GULP code [955, 956], one should take care that the simulation temperature is high enough for the classical dynamics to be valid. As a result of the MD simulation, one obtains a set of instantaneous atomic configurations (compound structure “snapshots”). These can be immediately used

to calculate the partial radial distribution functions (RDFs), which can be compared with those calculated from the diffraction data to exclude the unreliable evolution of the compound structure as MD is being run.

To implement the next step, two computer codes, EDAGULP and EDACA, were developed within the EDA project [957]. These are used to perform the configuration-averaged EXAFS calculation using the *ab initio* multiple-scattering (MS) code FEFF8 [937] and the results of the MD simulations by GULP [955,956]. The first code EDAGULP converts the output of the MD GULP run into that required by the EDACA code and also calculates partial RDFs for a further analysis. The EDACA code is used to perform a repeated automatic run of the FEFF8 code for each of the atomic configurations, extracted from the MD simulation, and to calculate the configuration-averaged EXAFS signal. Note that the input file required by the FEFF code is automatically generated by the EDACA code. Such an approach is rather time consuming computationally, since the number of atomic configurations, required to get a good average, is normally about a few thousand. However, it allows the final result to be obtained in a reasonable time ranging from a few hours to one day on a modern PC compatible computer. Since the EXAFS calculations for each of the atomic configurations can be performed independently, this stage is easily parallelizable. A full simulation scheme (Fig. 9.19) is currently being implemented on a “LASC” cluster-type computer at Institute of Solid State Physics (Riga) [966].

The simulated configuration-averaged EXAFS signal accounts for thermal disorder and can be directly compared with the experimental one, with respect to the size of the MD box, which determines the most distant coordination shell contributing to the EXAFS signal. Let us also note that while we discuss here only the EXAFS simulation, the same scheme can be applied to the calculation of the X-ray absorption near the edge structure (XANES), although this task is much more difficult computationally due to the time required to calculate the XANES signal for a single atomic configuration.

Further we provide an example of applying of the above-discussed scheme to the Ti K-edge EXAFS in the perovskite SrTiO_3 [949].

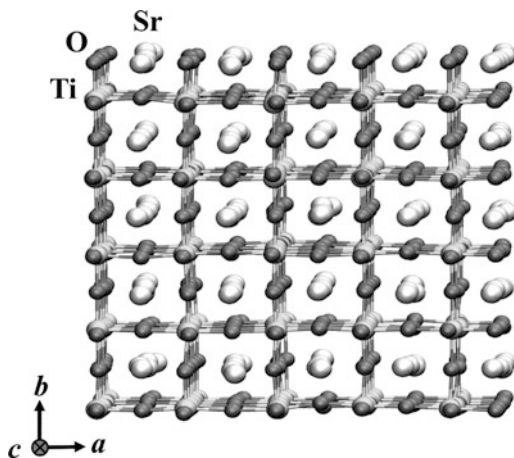
The quantum mechanics calculation of a cubic SrTiO_3 was performed by the *ab initio* CRYSTAL06 code [953] within the linear combination of atomic orbitals (LCAO) approximation and the hybrid Hartree–Fock (HF)–density-functional theory (DFT) approach with the B3PW exchange-correlation functional [958]. The calculated Mulliken effective atomic charges $Z_{\text{Sr}} = 1.84$, $Z_{\text{Ti}} = 2.36$, $Z_{\text{O}} = -1.40$ were used further in the MD simulations.

The MD simulations of SrTiO_3 were performed in the NVT ensemble using the rigid-ion vibrational model within the quasiharmonic approximation as implemented in the GULP code [955,956]. The short-range pairwise repulsive interactions Sr–O, Ti–O, and O–O (see Table 9.43) were described by the Born–Mayer potential $U(r) = A \exp(-r/\rho)$ acting over the range of 0–15 Å. The long-range Coulomb interactions were evaluated using the Ewald summation method [962] with three effective charges of strontium (Z_{Sr}), titanium (Z_{Ti}), and oxygen (Z_{O}) ions. The requirement of charge neutrality is that $Z_{\text{Sr}} + Z_{\text{Ti}} + 3Z_{\text{O}} = 0$. The values

Table 9.43 Parameters of the Born–Mayer (from [959]) and Coulomb potentials, used in the MD calculations of cubic SrTiO_3 ($a = 3.905 \text{ \AA}$ [961])

Pairs of atoms	$A(\text{eV})$	$\rho(\text{\AA})$	
Sr–O	1769.51	0.319894	
Ti–O	14567.4	0.197584	
O–O	6249.17	0.231572	
Atoms	$Z(\text{e})$	$Z_{\text{LCAO}}(\text{e})$	$Z(\text{e})$
Sr	1.84	1.84	1.84
Ti	1.85	2.36	3.02
O	−1.23	−1.40	−1.62

Fig. 9.20 Snapshot of the $5 \times 5 \times 5$ supercell of SrTiO_3 used in the MD simulation

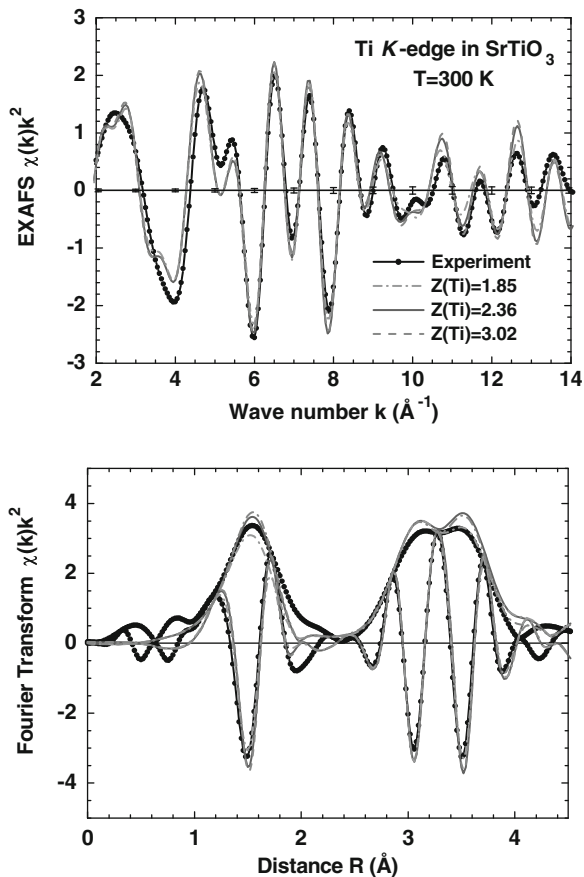


of charges were first taken from the LCAO calculations, but the influence of the Ti and O charge variation was also studied.

The simulations were performed for three different MD boxes (Fig. 9.20) with periodic boundary conditions. They were constructed basing on supercells composed of 27 ($3 \times 3 \times 3$), 125 ($5 \times 5 \times 5$), or 343 ($7 \times 7 \times 7$) unit cells, which contain 135, 625 and 1,715 atoms, respectively. The integration of Newton's equations was performed by the leapfrog Verlet method. In each simulation, the structure was equilibrated at 300 K, corresponding to the temperature of the EXAFS experiment [952], and a set of instantaneous atomic configurations was accumulated with a time interval 20–80 ps with a time step 1 fs. The number of recorded configurations, used further in the EXAFS calculations, was between 1,000 and 4,000.

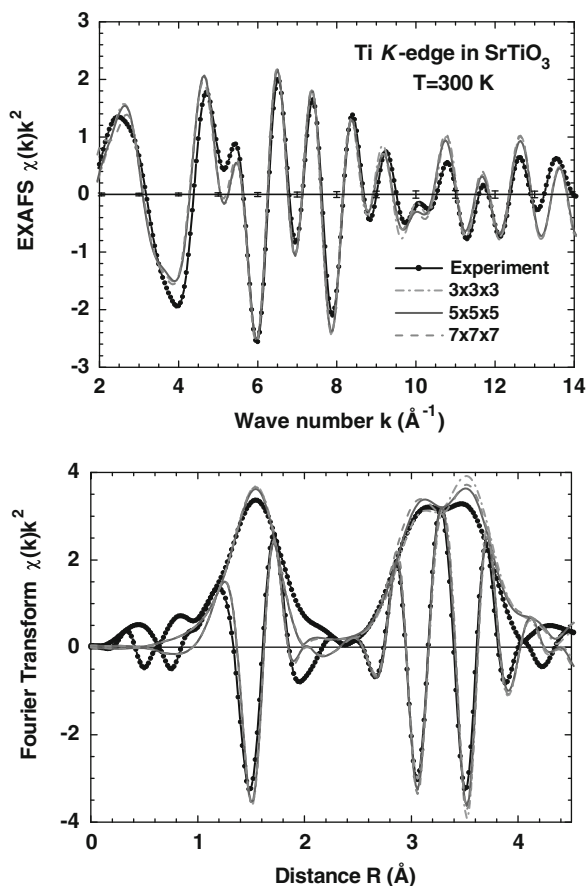
The total EXAFS signals were generated for each configuration by the FEFF8 code [937] with regard to all the multiple-scattering (MS) contributions with the half path length below 5 $\text{\AA}$, which covers the range up to the fourth titanium coordination shell, composed of 24 oxygen atoms. At the first stage of the MS calculations, the scattering potentials and phase shifts should be evaluated for all significantly different atoms in the structure [937]. In our case, since one has a large

Fig. 9.21 Effect of the titanium ions charge on the calculated EXAFS $\chi(k)k^2$ signals (*upper panel*) and their Fourier transforms (*lower panel*) for SrTiO_3 in the range up to the 4th coordination shell. The dash-dotted curve corresponds to $Z_{\text{Ti}} = 1.85$, the solid to $Z_{\text{Ti}} = 2.36$, and the dashed to $Z_{\text{Ti}} = 3.02$. The experimental signals (from [952]) are shown by solid circles. Note that the Fourier transforms are not corrected by the phase shift; therefore, the peaks positions differ from crystallographic values. The error bars for the experimental EXAFS signal are also shown. See text for the calculation details



number of slightly different atomic configurations, two approaches to this problem are possible: (a) one can perform the calculations for the average configuration and neglect the variation of the scattering potentials due to thermal vibrations, or (b) one can recalculate the scattering potentials at each MD time step. Here we use the first approach to significantly reduce the computation time; moreover, we believe that this approximation is generally good enough in the EXAFS region for $k \geq 2 \text{ \AA}^{-1}$. Thus, the scattering potentials and phase shifts were calculated only once for a cluster with a radius of $8 \text{ \AA}$, having the structure of the cubic SrTiO_3 and centered at the Ti atom. The complex exchange-correlation Hedin–Lundqvist potential and default values of muffin-tin radii, as provided within the FEFF8 code [937], were used. The value of the amplitude reduction factor S_0^2 due to many-body effects was set to 0.67, as was found in [952]. The Ti K-edge EXAFS spectra in SrTiO_3 and their Fourier transforms (FT), calculated using the approach described in the previous sections, are shown in Figs. 9.21 and 9.22, respectively. Note that no fitting parameters were used in the calculations. In

Fig. 9.22 Effect of the supercell size on the calculated EXAFS $\chi(k)k^2$ signals (*upper panel*) and their Fourier transforms (*lower panel*) for SrTiO₃ in the range up to the 4th coordination shell. The *dash-dotted curve* corresponds to the supercell size (3×3×3), the solid to (5×5×5), and the dashed to 7×7×7. The experimental signals (from [952]) are shown by *solid circles*. Note that the Fourier transforms are not corrected by the phase shift; therefore, the peaks positions differ from the crystallographic values. The error bars for the experimental EXAFS signal are also shown in (a)



general, the agreement between the experimental and theoretical configuration-averaged EXAFS signals is good. However, the difference between two EXAFS signals is larger than the experimental error bars. Further improvements are possible by optimizing the parameters of interatomic potentials to fit the EXAFS signal—this procedure is under development.

Both the amplitude and phase of the EXAFS and FT signals in the range up to 4 $\text{\AA}$ around the central Ti atom are rather well reproduced. This region corresponds to the first four coordination shells and includes also the contributions from the multiple-scattering (MS) effects within the first (6 oxygen) and third (6 titanium) coordination shells [963]. Note that the MS signals, generated within the linear O–Ti₀–O and Ti₀–O–Ti (Ti₀ is the absorbing atom) atomic chains, are known [964, 965] to produce the largest contributions into the EXAFS signal and are also sensitive to the respective bonding angles. Thus, the first peak in FT at about 1.5 $\text{\AA}$ corresponds to 6 oxygen atoms in the first shell. The second peak at about 3.1 $\text{\AA}$ is due to 8 strontium atoms in the second shell plus the MS contribution from the

first shell. The third peak at about 3.5 Å originates from 6 titanium atoms in the third shell, including the respective MS contributions, and 24 oxygen atoms in the fourth shell.

In Fig. 9.21, the influence of the Ti atomic charge on the configuration-averaged EXAFS signal is shown. One can see that the small but significant variation of the Ti charge from the value $Z_{\text{Ti}} = 2.36$, obtained in the LCAO calculation, down to 1.85 and up to 3.02 does not influence the result crucially. The weak sensitivity of the EXAFS signal to the atomic charge means that the atomic charge should not be used in the potential optimization procedure, but can be determined from *ab initio* calculations, as suggested in the QM–MD approach (see Fig. 9.19). Moreover, it means that the relatively small differences in Mulliken and Bader atomic charges can be ignored in the Coulomb part of the interatomic potentials.

The influence of the supercell size on the configuration-averaged EXAFS signal is shown in Fig. 9.22. Note that for the smallest supercell, having a size of $3 \times 3 \times 3$ unit cells, half of its linear dimension $3a/2 = 5.86$ Å ($a = 3.905$ Å is the lattice parameter of SrTiO_3 [960, 961]) is larger than the size (up to 4 Å) of the region compared in FT. Therefore, a small difference in the total EXAFS signal, observed mainly in the amplitude of the peaks at 3.1 and 3.5 Å, can be explained by the interaction between the atoms of the central supercell and their periodic images in the neighboring cells. Comparing the results for the three supercells, one can see that when the supercell size increases, this effect decreases. In fact, the EXAFS signals for the supercells, having the sizes $(5 \times 5 \times 5)$ and $(7 \times 7 \times 7)$ unit cells, are close. This means that the $5 \times 5 \times 5$ supercell size is already sufficient in our case to obtain reliable results up to the fourth coordination shell.

In [950] the temperature-dependent Re L_3 -edge EXAFS signals from perovskite-type cubic ReO_3 were successfully interpreted using a combination of the classical NVT molecular dynamics (MD) and *ab initio* multiple-scattering approach. First, the first-principles calculations were performed for cubic ReO_3 using the hybrid B3PW exchange-correlation potential with the $2 \times 2 \times 2$ supercell by the LCAO (linear combination of atomic orbitals) CRYSTAL code [953]. As a result, the Mulliken atomic charges were determined, and the phonon frequencies at high symmetry points (G , R , M , X) of the Brillouin zone were calculated by the frozen phonon method [968].

Next, the force field potential model was chosen in the form of the Buckingham and covalent exponential interatomic potentials to describe the Re–O and O–O bonding (Table 9.44). The model parameters, including ions charges, were optimized using a simulated annealing method to reproduce a set of experimental data (lattice parameter [969], elastic constants, and bulk modulus [970]) and theoretically calculated phonon frequencies.

The perovskite-type ReO_3 structure consists of corner-linked ReO_6 regular octahedra with Re atoms at the centers and linear Re–O–Re chains. The space between eight octahedra forming the cube is fully vacant, which allows a significant rotation of the ReO_6 units [969] and results in the anisotropy of oxygen atom thermal vibration. The obtained MD trajectories in the (100) plane for 573 K confirm that the amplitude of the oxygen thermal vibrations is larger in the direction perpendicular

Table 9.44 Parameters of the optimized Re–O and O–O pairwise potentials used in the MD simulations. For the parameter definition, see [955]

Coulomb potential			
Atom	Z(e)		
Re	3.36		
O	−1.12		
Buckingham potential, cutoff 20 Å			
Pair of atoms	A (eV)	$\rho(\text{\AA})$	C (eVÅ ⁶)
Re–O	1194.24	0.342561	98.0988
O–O	3224.54	0.265204	47.39861
Covalent exponential potential, cutoff 2 Å			
Pair of atoms	D (eV)	a (Å ^{−1})	r ₀ (Å)
Re–O	4.82827	6.21069	1.875

to the Re–O–Re chains, but the vibrations of Re atoms are isotropic. The recent pressure-dependent EXAFS study [967] suggests that even at normal conditions the Re–O–Re bond angle deviates from the linear one, observed by diffraction, and is equal to about 172°. These temperature-dependent MD simulations allowed the estimation of the mean value of the Re–O–Re angle from the angle distributions (Fig. 9.13) to be 174.5° at 300 K, 173.0° at 423 K, and 172.2° at 573 K. The decrease in a mean angle value indicates a larger amplitude of oxygen vibrations at higher temperatures.

The reliability of the MD simulations under consideration is well supported by good agreement between the experimental and theoretical Re L₃-edge EXAFS signals observed in the simulation range up to about 6 Å that includes the first five coordination shells around the absorbing Re atom. In Fig. 9.21 the two EXAFS $\chi(k)k^2$ signals and the corresponding Fourier transformations (FTs) at 300 K are compared. The effect of the supercell size on the calculated EXAFS signals is shown in Fig. 9.22. The SS and MS contributions are shown in Figs. 9.21 and 9.22 and allow one to conclude unambiguously on the origin of the peaks in FTs. As has been suggested before [971], the peak at 2.2–3.0 Å is due to the pure MS effects from the first shell, and the MS contributions within the next two main peaks at 3.6 Å and 5.0 Å are about 30–40%.

The QM–MD approach considered opens a direct way for the interpretation of EXAFS spectra in nanocrystalline materials, taking into account their “true” structure and dynamics, without any need for the oversimplified models being used currently. Finally, a refinement of the interatomic potentials based on the EXAFS spectra, that is, the solution of the inverse problem, can be also performed, although this task is very demanding computationally.

9.4 LCAO Calculations on Tungstates MeWO₄ (Me: Zn,Ni)

9.4.1 Electron and Phonon Properties of ZnWO₄

Zinc tungstate ZnWO₄ is a technologically important material which has a number of applications such as scintillators, laser hosts, optical fibers, sensors, and phase-change optical recording [972–976].

The crystal structure of ZnWO₄ was determined by neutron [977] and X-ray powder diffraction [978]. ZnWO₄ has monoclinic wolframite-type structure with the space group $P2/c$. There are two formula units per primitive cell, having the lattice parameters $a = 4.69263 \text{ \AA}$, $b = 5.72129 \text{ \AA}$, $c = 4.92805 \text{ \AA}$ and $\beta = 90.6321^\circ$ [977]. The presence of two nonequivalent oxygen atoms is responsible for three pairs of Zn–O and W–O bonds, having different lengths. Thus, both Zn and W atoms are surrounded by six oxygens, forming a distorted octahedral coordination. The WO₆ octahedra distortion was directly observed by the W L₃-edge X-ray absorption spectroscopy in [979].

The lattice dynamics of ZnWO₄ was probed by Raman scattering in [980, 981] and interpreted on the basis of the octahedral WO₆ groups vibrations. The luminescent properties of ZnWO₄ have been widely studied [982–985] and are determined by a charge transfer between the oxygen and tungsten ions in the WO₆ molecular complex [986].

The electronic structure of ZnWO₄ has been very little studied. The cluster discrete variational $X\alpha$ (DV- $X\alpha$) method was used in [987] to understand the origin of the valence and conduction bands. It underestimated the value of the bandgap (2.63 eV calculated vs. 4.6 eV [982] and 4.9 eV [987] experimental) but was rather successful in describing the X-ray photoelectron spectrum (XPS) [987].

Recently, the electronic structure of the [WO₆]^{6−}–Zn²⁺ complex in the ZnWO₄ crystal has been calculated by the configuration interaction method within the embedded cluster approach to explain the intrinsic luminescence of tungstate [988]. The influence of the point defects such as oxygen and zinc vacancies on the electronic structure of the complex has been also studied [988].

The first ab initio calculations of wolframite-type ZnWO₄ were performed in [989]. The structural and electronic parameters of a wolframite-type ZnWO₄ crystal were calculated using the periodic LCAO approach. The obtained results were compared with the low-temperature X-ray diffraction data [978] and the X-ray photoelectron spectrum [987]. All the calculations were carried out using the CRYSTAL code [953]. To avoid the core electrons of tungsten and zinc atoms, the effective core potentials (ECP) from [991] and [884] were chosen: the large-core ECP68 for the W ($Z = 74$) atom (68 electrons in the core) and the small-core ECP18 for the Zn ($Z = 30$) atom (18 electrons in the core). Note that the Hay–Wadt ECP68 [991] was used to describe the structural and electronic properties of the bulk tungsten trioxide WO₃ and to explain the observed instability of the cubic WO₃ [992], providing good agreement between the calculated structural parameters for the tetragonal WO₃ and available experimental data. The use of ECP18 allows

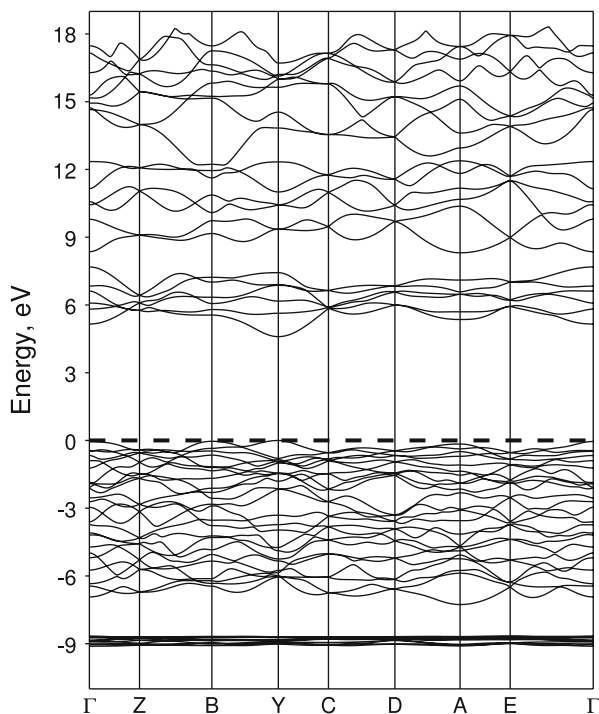
Table 9.45 Comparison of lattice parameters (a , b , c , β) and atomic fractional coordinates (x , y , z), calculated using LDA, PW91, PBE, B3PW, B3LYP, and PBE0 Hamiltonians, with the low-temperature (12 K) X-ray diffraction data from [978] for a wolframite-type ZnWO_4 . The total atomic charges (Q), following the Mulliken population analysis scheme, are also given. The experimental values of the energy bandgap E_g was taken from [982,987]

	LDA	PW91	PBE	B3PW	B3LYP	PBE0	Exp
a (Å)	4.606	4.696	4.705	4.669	4.693	4.660	4.683
b (Å)	5.702	5.909	5.928	5.840	5.947	5.805	5.709
c (Å)	4.795	4.866	4.870	4.831	4.857	4.820	4.923
β (°)	88.74	88.95	89.05	89.45	89.32	89.62	90.54
Zn (y)	0.687	0.695	0.698	0.697	0.700	0.697	0.681
W (y)	0.205	0.207	0.206	0.202	0.205	0.201	0.181
O1 (x)	0.221	0.220	0.220	0.218	0.219	0.218	0.230
O1 (y)	0.896	0.895	0.895	0.895	0.893	0.895	0.885
O1 (z)	0.449	0.458	0.458	0.454	0.459	0.453	0.430
O2 (x)	0.253	0.247	0.247	0.246	0.245	0.247	0.269
O2 (y)	0.387	0.382	0.382	0.379	0.378	0.379	0.380
O2 (z)	0.409	0.409	0.410	0.408	0.409	0.407	0.406
Q (Zn)	1.48	1.50	1.50	1.55	1.54	1.57	–
Q (W)	3.58	3.52	3.51	3.72	3.76	3.75	–
Q (O1)	–1.32	–1.30	–1.30	–1.37	–1.38	–1.38	–
Q (O2)	–1.22	–1.21	–1.21	–1.27	1.28	–1.28	–
E_g (eV)	2.31	2.33	2.31	4.27	4.22	4.60	4.6, 4.9

one to include Zn 3d-electrons in the valence shell, which is known to be important for the transition-metal compounds. The basis set corresponding to the ECP18 [884] was chosen for Zn atom; the diffuse Gaussian-type orbitals with exponents less than 0.06 were excluded to avoid the basis set linear dependence. The basis set optimized in the calculations of the cubic WO_3 crystal [992] was adopted for the W atom. The all-electron basis set, optimized in the earlier calculations of perovskites [590], was used for the O atoms. In the CRYSTAL code, the accuracy in the evaluation of the Coulomb and exchange series is controlled by a set of tolerances, which were taken to be the default values (6,6,6,6,12). The Monkhorst–Pack scheme [85] for the $8 \times 8 \times 8$ $\mathbf{k}$ -point mesh in the Brillouin zone was applied. The total spin projection $S_z = 0$ was fixed in the calculation of the closed-shell ground state of the insulating ZnWO_4 crystal. The SCF calculations were performed for three pure DFT (LDA [339], PW91 [342], PBE [344]) Hamiltonians and three hybrid HF–DFT (B3PW [993], B3LYP [361], PBE0 [393]) Hamiltonians. The optimized values of the structural parameters are given in Table 9.45. The experimental data were taken from the low-temperature (12 K) X-ray diffraction [978].

A sum of squared differences between the calculated and experimental structural parameters was used to compare the results for different Hamiltonians. All the parameters were divided into three groups: the first group consists of three lattice constants (a , b , c), the second one contains the angle β , and the third one—three atomic fractional coordinates (x , y , z). Lattice constants and atomic fractional

Fig. 9.23 Band-structure diagram for a wolframite-type ZnWO_4 . The energy zero is set at the Fermi energy level

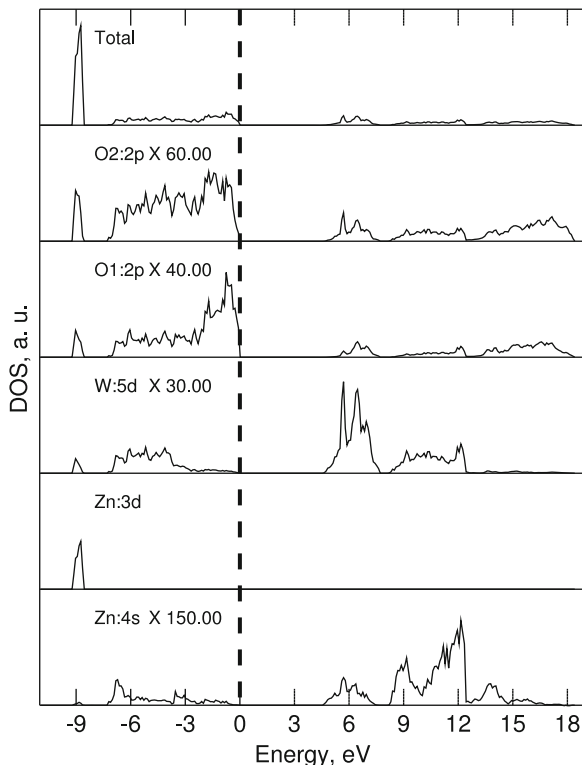


coordinates are best reproduced by the LDA and PBE0 Hamiltonians, whereas the value of the angle β agrees best of all in the case of the hybrid HF–DFT B3PW and PBE0 Hamiltonians. The differences for the three lattice constants do not exceed 4%, the angle β is reproduced within 2%, and atomic fractional coordinates—within 14%. Taking into account the differences for all the parameters, the hybrid HF–DFT PBE0 Hamiltonian produces the best overall agreement with the experimental data [978]; therefore, we will further discuss only the results based on it.

The calculated energy dispersion curves and the PDOS for the hybrid HF–DFT PBE0 Hamiltonian are shown in Figs. 9.23 and 9.24, respectively. The dispersion curves are plotted along eight different symmetry directions in the Brillouin zone. Note that the band-structure diagrams for the other Hamiltonians have a qualitatively similar appearance but a significant difference in the bandgap value (Table 9.45), which is significantly smaller in the pure DFT Hamiltonians than expected [1145].

The narrow subband observed at about -9 eV corresponds to the Zn 3d states and is well separated from the other bands. The upper part of the valence subband (-7.5 – 0 eV) is due mostly the O 2p states, mixed with the W 5d states, whereas the lower part is composed of the O 2p and W 5d states with some admixture of the Zn 4s states. The highest state in the valence band for the pure DFT methods is located at the B point, while the states at Γ , Y, and A points are very close in the energy values. A similar situation occurs for the hybrid Hamiltonians, although here the highest state is located at the Y point. The bottom of the conduction band

Fig. 9.24 Total/projected density of states for a wolframite-type ZnWO_4 . The energy zero is set at the Fermi energy level



is composed mostly of the $\text{W } 5d$ states; however, an admixture of the $\text{O } 2p$ and some of the $\text{Zn } 4s$ states is clearly observed along overall the conduction band. The lowest-energy state in the conduction band is located at the Y point of the Brillouin zone for all the Hamiltonians.

To conclude, the minimum bandgap for the PBE0 Hamiltonian, which is the best in the reproduction of structural parameters, occurs at the Y point of the Brillouin zone and corresponds to a direct transition. The calculated bandgap value $E_g = 4.6 \text{ eV}$ is in good agreement with the experimental values 4.6 eV [982] and 4.9 eV [987].

In Fig. 9.25, we show different electron-density maps in the two most representative (001) and (110) planes. The (001) passes through the Zn, W, and three O atoms. One can see that the electron density around the W atom is distorted due to a displacement of the W atoms from the center of oxygen octahedra, caused by the second-order Jahn–Teller effect. The electron density around the Zn atoms is relatively symmetric. The second (110) plane passes through the Zn and W atoms only. There is an electron-density distortion around both atoms, indicating that the oxygen octahedra around the Zn atoms are also deformed.

The comparison between the XPS spectra [987] and the PDOS curves calculated using the PBE0 is shown in Fig. 9.26. The binding energy of the PDOS curves is

Fig. 9.25 Difference electron-density maps in (001) (*top plot*) and (110) (*bottom plot*) planes for the wolframite-type ZnWO_4 . The solid, dashed, and dot-dashed lines correspond to positive, negative, and zero difference, respectively

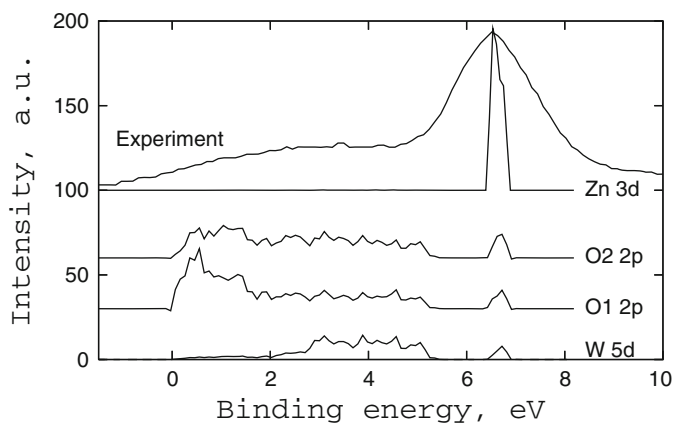
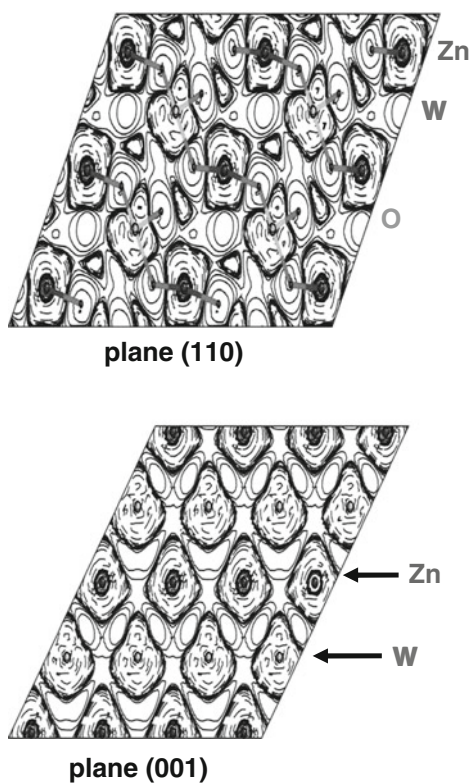


Fig. 9.26 Comparison of XPS spectrum and PDOS curves for the wolframite-type ZnWO_4 . The curves are vertically shifted for the sake of clarity

given relative to the Fermi level placed at the top of the calculated valence band. The energy scale of the XPS spectrum was modified for the best agreement of the main sharp peak in the experimental signal with the Zn $3d$ PDOS position. The low binding energy broad peak of the XPS spectrum is attributed to the O $2p$ states with some admixture of the W $5d$ states. The overall agreement between the calculated splitting of the O $2p$ states and the Zn $3d$ states and the two peaks in the XPS spectrum is very good, better than the one found previously within the cluster DV- $X\alpha$ method [987].

Summing up we note that the results obtained for all the Hamiltonians differ from the experimental values by less than 14%, while all the structural and electronic parameters are best reproduced by the hybrid PBE0 Hamiltonian. The PBE0 structural parameters of CaWO_4 (see [968]) are also reproduced in good agreement with the experimental data given in [978].

The B3PW and PBE0 phonon frequencies of MeWO_4 (Me = Zn,Ca) were calculated by the frozen phonon method in [968] and also agree rather well with those obtained by infrared and Raman spectroscopies.

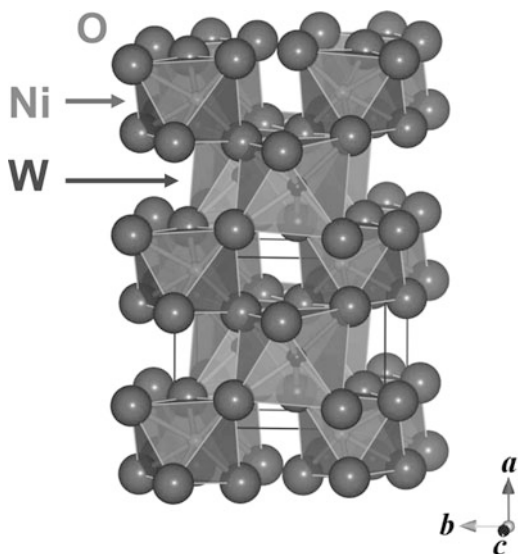
In ZnWO_4 the tungsten–oxygen chemical bonding is covalent due to the electron-density transfer to oxygen atoms, whereas the zinc atoms show a more ionic behavior. The calculated density of states is in good agreement with the XPS spectrum. The main contribution to the valence band is due to the Zn $3d$ states at high binding energies and the O $2p$ and W $5d$ characters at low and medium binding energies.

The ZnWO_4 crystals have a complete $3d$ shell of the Zn atom and are nonmagnetic at room temperature. The tungstates MeWO_4 (Me = Fe,Co,Ni,Cu) have an incomplete $3d$ shell and are paramagnetic at room temperature.

9.4.2 Magnetic Ordering in NiWO_4

Nickel tungstate (NiWO_4) has been extensively studied because of its use for catalysts [995–998], humidity [999] and gas sensors [1000], in microwave devices [1001], and photoanodes [1002, 1003]. The application of mixed nickel–tungsten oxide thin films to electrochromic systems has also been proposed [1004]. In such systems, the formation of the NiWO_4 phase can occur at nano- or microscale resulting in a modification of their chromogenic properties. The properties of electrochromic materials are determined by charge insertion/extraction accompanied by the changes in the local atomic and electronic structures [1005]. Many years these phenomena have been studied for pure WO_3 and NiO both experimentally and theoretically [1006–1008], yet fundamental studies on mixed systems as well as pure NiWO_4 are rather limited. In particular, the band-structure calculations of NiWO_4 not had been performed at all before the paper [994] appeared. NiWO_4 is isomorphous to other transition-metal tungstates such as MnWO_4 , FeWO_4 , CoWO_4 , and ZnWO_4 [1009], which, except for ZnWO_4 , have an incomplete $3d$ shell and are paramagnetic at room temperature. At low temperatures, MnWO_4 , FeWO_4 ,

Fig. 9.27 Crystal structure ($2a$, b , c) of the monoclinic ($P2/c$) NiWO_4 [1009, 1012]. The crystallographic unit cell is indicated



CoWO_4 , and NiWO_4 undergo cooperative transitions to antiferromagnetically ordered states [1010]. It should be noted that in the last few years MnWO_4 has attracted increased attention as a multiferroic material [1011].

The crystal structure of NiWO_4 was determined at room temperature by X-ray [1009] and neutron [1012] powder diffraction. It is monoclinic wolframite-type structure with the space group $P2/c$. There are two formula units ($Z = 2$) per primitive cell, having the lattice parameters $a = 4.5992 \text{ \AA}$, $b = 5.6606 \text{ \AA}$, $c = 4.9068 \text{ \AA}$, and $\beta = 90.03^\circ$ [1012]. The presence of two nonequivalent oxygen atoms is responsible for three pairs of Ni–O and W–O bonds, having different lengths. Thus, both the Ni and W atoms are surrounded by six oxygen atoms, forming a distorted octahedral coordination, which was directly probed by the W $L_{1,3}$ and Ni K edges X-ray absorption spectroscopy in [1013, 1014]. Metal–oxygen octahedra of one type share edges and form zigzag chains along the c -axis (Fig. 9.27). The antiferromagnetic order exists in NiWO_4 below 67 K [1015]. Its magnetic unit cell ($2a$, b , c) is double the crystallographic one along the a -axis [1010]. The spins at nickel ions in the same chain are arranged collinearly (coupled ferromagnetically) but are antiparallel (coupled antiferromagnetically) to the spins in the adjacent chain.

The electronic, structural, and phonon properties of the antiferromagnetic wolframite-type NiWO_4 were studied in [994] using first-principles spin-polarized LCAO calculations based on the hybrid Hartree–Fock (HF)/density-functional (DFT) scheme. The influence of different percentages of HF contribution, that is, different correlation strength, on the structure and phonon frequencies was investigated and compared with the available experimental data. An optimized atomic basis was used in the calculations [994]. The methodology used in [994] had been employed to ZnWO_4 in [968, 989], where the electronic, structural, and phonon

properties of tungstate were studied within the LCAO method. The best agreement between the experimental and theoretical structural and electronic parameters of ZnWO_4 was found for the hybrid PBE0 (25%) Hamiltonian. However, the infrared (IR) and Raman phonon bands in ZnWO_4 were reproduced rather qualitatively [968]: in particular, the theory tends to overestimate the Raman phonon frequencies, especially at high frequencies, where the observed difference reaches $\sim 34 \text{ cm}^{-1}$.

NiWO_4 represents an even more complicated case, since at low temperatures ($\leq 67 \text{ K}$), it undergoes cooperative transition to an antiferromagnetically (AF) ordered state [1015]. To avoid the core electrons of tungsten and nickel atoms, the Hay–Wadt (HW) effective small-core potentials (ECP) and the corresponding atomic basis sets for metal atoms (W, Ni) were used, excluding the diffuse Gaussian-type orbitals. The basis set for tungsten was optimized for ZnWO_4 [968], whereas the starting basis set for nickel was taken from [1016] and reoptimized for NiWO_4 . The all-electron basis set, optimized in the earlier calculations of perovskites [590], was used for oxygen atoms.

The calculations were performed for four magnetic states by fixing the total spin projection. The first state (AF1), having the total spin projection $S_z = 0$, corresponds to that observed experimentally [1012, 1015] with the ferromagnetic ordering of spins at nickel ions within zigzag chains but antiferromagnetic alignment between different chains (Fig. 9.27). Note that the AF1 state requires the doubling of the crystallographic unit cell along the *a*-axis direction. There is also another possibility for the antiferromagnetic state (AF2) with $S_z = 0$ when spins at nickel ions in the same chain have an antiparallel arrangement: in this case, no cell doubling is required since there are two nickel ions per primitive cell. The ferromagnetic (FM) state with all the spins at nickel ions ordered collinearly and the nonmagnetic (NM) state were also calculated. The accuracy of the evaluation of the Coulomb and exchange series was controlled by a set of tolerances, which were taken to be (10^{-8} , 10^{-8} , 10^{-8} , 10^{-8} , 10^{-16}) to provide the high numerical accuracy. The Monkhorst–Pack scheme for the $8 \times 8 \times 8$ *k*-point mesh in the Brillouin zone was applied. The SCF calculations were performed for the hybrid Hartree–Fock—DFT Hamiltonian of PBE0-type was used with different percentages (0–25%) of Hartree–Fock contribution. The calculations of phonon frequencies were made by the direct (frozen phonon) method. The best agreement between the calculated and experimental phonon frequencies was observed for 13% HF contribution (PBE0 13%); therefore, only these results are given in Tables 9.46, 9.47 and will be discussed further.

The equilibrium lattice parameters have been calculated by minimizing the crystal total energy for three magnetic (AF1, AF2 and FM) and nonmagnetic (NM) states. Such simulations performed with no regard to any thermal effects are often referred to as conducted at temperature $T = 0 \text{ K}$ [1017]. The presence of thermal effects is expected to result in the lattice expansion and an increase in anharmonic contributions, thus shifting slightly the position of the vibrational bands and increasing their broadening. Both effects are known to be weak in tungstates [981, 1018] and, in any case, are much smaller than the accuracy of the calculations under consideration. In fact, the weak sensitivity of the vibrational

Table 9.46 Lattice parameters (a ; b ; c ; β), atomic fractional coordinates (x ; y ; z), total energy per formula unit (E_{tot}), and the nearest interatomic distances (Ni–O and W–O), calculated for magnetic (AF1, AF2, FM) and nonmagnetic (NM) states of wolframite-type NiWO₄ using PBE0-type Hamiltonian (13% HF). The room-temperature neutron powder diffraction (NPD) data [1012] are shown for comparison

	NPD	AF1	AF2	FM	NM
a (Å)	4.5992	4.6226	4.6240	4.6247	4.5877
b (Å)	5.6606	5.6866	5.6874	5.6882	5.6084
c (Å)	4.9068	4.9308	4.9319	4.9328	4.9518
β (°)	90.03	89.98	89.93	89.97	89.03
Ni(y)	0.6616	0.6584	0.6583	0.6586	0.6541
W(y)	0.1786	0.1798	0.1797	0.1800	0.1802
O1(x)	0.2241	0.2189	0.2187	0.2187	0.2218
O1(y)	0.1105	0.1071	0.1073	0.1071	0.1090
O1(z)	0.9204	0.9320	0.9318	0.9322	0.9276
O2(x)	0.2644	0.2590	0.2587	0.2586	0.2600
O2(y)	0.3772	0.3776	0.3773	0.3779	0.3807
O2(z)	0.3953	0.4038	0.4038	0.4035	0.4029
E_{tot} (eV)		−14625.740	−14625.732	−14625.734	−14624.420
R(Ni–O ₁)(Å)	1.994	2.067	2.066	2.068	2.032
R(Ni–O ₂)(Å)	2.061	2.049	2.051	2.053	2.027
R(Ni–O ₂)(Å)	2.068	2.090	2.091	2.090	2.066
R(W–O ₂)(Å)	1.803	1.809	1.809	1.809	1.814
R(W–O ₁)(Å)	1.957	1.911	1.911	1.911	1.921
R(W–O ₁)(Å)	2.107	2.119	2.120	2.121	2.114

bands of tungstates to thermal effects finds practical application as Raman-active crystals in solid-state lasers, based on the stimulated Raman scattering (SRS) [1019, 1020].

The calculated values of the structural parameters are compared in Table 9.46 with the experimental data obtained by neutron powder diffraction [1012]. One can see that the results for magnetic states, having close total energies, agree better than 0.03 Å with the experimental lattice constants and better than 0.1° for the angle β . The evaluated total energy per formula unit E_{tot} (Table 9.46) has the lowest value for the antiferromagnetic state AF1 and the highest value for the nonmagnetic state. The antiferromagnetic AF2 and ferromagnetic FM states have intermediate and close values of E_{tot} , with the latter being slightly lower. These results confirm the antiferromagnetic AF1-type ordering of spins in NiWO₄ observed experimentally at low temperatures [1012, 1015]. Note that in all the calculated magnetic states, the unpaired electrons are well localized at nickel atoms, giving a net atomic spin of about 1.70.

The Mulliken population analysis was used to estimate the total atomic charges. They are equal to +1.67e for Ni, +2.78e for W, −1.16e for O1, and −1.07e for O2 suggesting a mixed ionic-covalent character of the Ni–O and W–O bonding. In contrast to the purely ionic picture of a bare W⁶⁺ ion (with no valence electrons), the tungsten valence state in tungstate is around 3+ due to a back charge transfer

Table 9.47 Experimental and calculated (LCAO, PBE0-13% exchange-correlation functional) zero pressure frequencies (ν) of the vibrational modes in NiWO_4 . The experimental frequencies (ν_{expt}) were obtained from the room-temperature Raman signal. The Raman and infrared (IR) active(inactive) modes are denoted by A(I) for the nonmagnetic (NM) and ferromagnetic (FM) phases. In the antiferromagnetic AF2 phase, all the modes are both Raman and IR active. The first three acoustic modes (1, 2, and 3) are not given

Phonon mode	ν_{expt} (cm^{-1})	Phonon symmetry	NM		FM		AF2		ν (cm^{-1})
			ν (cm^{-1})	Raman	IR	ν (cm^{-1})	Raman	IR	Phonon symmetry
4	97	B_g	84	A	I	84	A	I	B
5	149	A_g	134	A	I	134	A	I	A
6		B_u	143	I	A	143	I	A	B
7	174	B_g	171	A	I	171	A	I	B
8		B_u	181	I	A	181	I	A	B
9	197	B_g	189	A	I	189	A	I	B
10	210	B_g	202	A	I	202	A	I	B
11	223	A_g	240	A	I	240	A	I	A
12	287	B_g	259	A	I	259	A	I	A
13		B_u	279	I	A	279	I	A	B
14		A_u	283	I	A	283	I	A	B
15	307	A_g	302	A	I	302	A	I	B
16		B_u	317	I	A	317	I	A	A
17	326	B_g	336	A	I	336	A	I	B
18		A_u	358	I	A	358	I	A	B
19		B_u	384	I	A	384	I	A	A
20	363	A_g	393	A	I	393	A	I	A
21		A_u	402	I	A	402	I	A	A
22		A_u	432	I	A	432	I	A	B
23	380	B_g	438	A	I	438	A	I	A
24	418	A_g	471	A	I	471	A	I	A
25		B_u	494	I	A	494	I	A	B
26		B_u	523	I	A	523	I	A	B
27		A_u	533	I	A	533	I	A	A
28	512	B_g	539	A	I	539	A	I	A
29	549	A_g	586	A	I	586	A	I	B
30	675	B_g	681	A	I	681	A	I	B
31		A_u	681	I	A	681	I	A	A
32	697	A_g	700	A	I	700	A	I	A
33	775	B_g	863	A	I	863	A	I	B
34		B_u	877	I	A	877	I	A	B
35		A_u	961	I	A	961	I	A	A
36	893	A_g	982	A	I	982	A	I	A

from the nearest oxygen atoms. This fact is responsible for a strong distortion of the WO_6 octahedra caused by the second-order Jahn–Teller effect [1021]. As a result, there are three significantly different W–O bonds having lengths of about 1.81 Å, 1.91 Å, and 2.12 Å (Table 9.46).

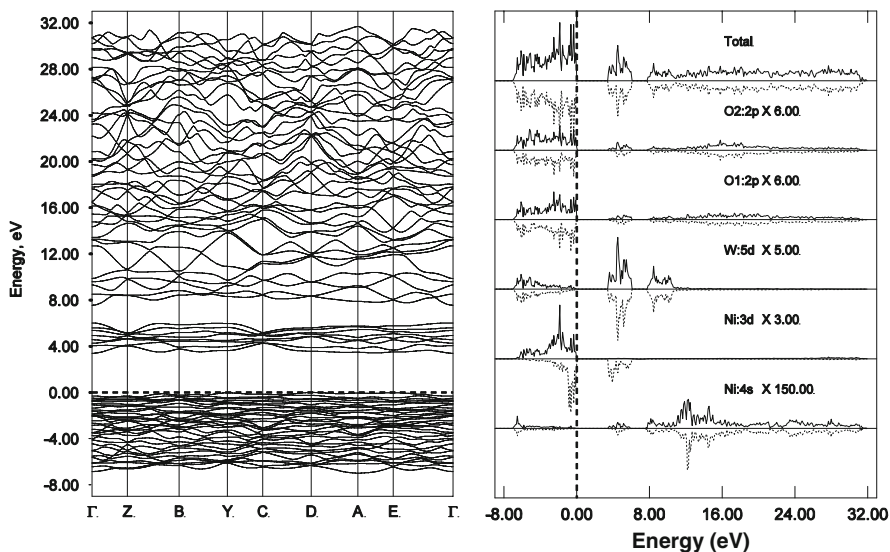


Fig. 9.28 Band-structure diagram (*left panel*) and the spin- dependent total/projected density of states (*right panel*) for the wolframite-type ($P2/c$) NiWO_4 in the antiferromagnetic AF2 state. The energy zero is set at the Fermi energy level

The band-structure diagram and the spin-dependent total/projected density of states for the wolframite-type NiWO_4 in the antiferromagnetic state are shown in Fig. 9.28. The dispersion curves are plotted along each of the eight different symmetry directions in the Brillouin zone. According to the calculations [994], NiWO_4 has an indirect bandgap ($E \rightarrow \Gamma$ or $A \rightarrow \Gamma$). The calculated bandgap value $E_g = 3.7$ eV is in good agreement with the experimental one equal to 3.6 eV [1002]. Note that a smaller value of the bandgap in NiWO_4 (2.28 eV in [1003] and 2.52 eV in [1022]) was also reported. These two numbers are underestimated due to an incorrect bandgap estimate in [1003]. It seems that the low quality measurements performed in a limited energy range (from 1.4 to 3.4 eV) on NiWO_4 thin films in [1003] have led to the confusion of the bandgap with the absorption bands due to the $d-d$ transitions at Ni^{2+} ions that are responsible for the color of the compound [1002, 1023].

The calculated electronic structure in NiWO_4 can be compared to that in other wolframite-type monoclinic ($P2/c$) tungstates such as CdWO_4 [1024], FeWO_4 [1025], CoWO_4 [1025], and ZnWO_4 [968, 989], as well as in the triclinic CuWO_4 [1026]. Most of the previous first-principles calculations were based on DFT functionals and underestimate the bandgap values: $E_g = 2.9$ eV versus $E_g(\text{exp}) = 3.8\text{--}4.09$ eV in CdWO_4 [1024], $E_g = 1.78$ eV versus $E_g(\text{exp}) = 2.0$ eV in FeWO_4 [1025], $E_g = 1.36$ eV [1025] versus $E_g(\text{exp}) = 2.0$ eV [1027] in CoWO_4 , and $E_g = 1.9$ eV [1026] versus $E_g(\text{exp}) = 2.06$ eV [1028] and 2.3 eV [1022, 1029] in CuWO_4 . However, the use of hybrid Hamiltonians within the LCAO method

allowed us to obtain for ZnWO_4 the bandgap energy $E_g = 4.6$ eV [989] and 5.4 eV [968] in better agreement with the experimental values $E_g(\text{exp}) = 4.6$ eV [1030] and 4.9 eV [987].

Previous band-structure calculations for these tungstates allow one to conclude that FeWO_4 [1025] and CoWO_4 [1025] have an indirect bandgap as was also found for NiWO_4 , whereas CdWO_4 [1024] and ZnWO_4 [968, 989] have a direct bandgap. Note that the indirect bandgap was also found experimentally from optical absorption spectra in CuWO_4 [1022, 1029]. The difference between the two groups of tungstates is connected with the contribution of the partially filled 3d states, provided by Fe^{2+} , Co^{2+} , Ni^{2+} , and Cu^{2+} ions, to the band structure. In the case of NiWO_4 (Fig. 9.28), the valence band is formed by the hybridized $\text{O}2p$ and $\text{Ni}3d$ states, and the $\text{Ni}3d(t_{2g}, e_g \uparrow)$ states contribute mainly to the upper part of the valence band. The conduction band is formed by the empty $\text{W}5d$ states with an admixture of the empty $\text{Ni}3d(e_g \downarrow)$ states at the bottom of the band. These results agree well with those obtained recently by optical and ultraviolet photoelectron spectroscopy in [1002].

As we have seen in this chapter, the HF and DFT LCAO methods, implemented in the computer code CRYSTAL, provide efficient computational schemes for the study of different properties of periodic systems. Real-solid properties depend in many cases on the point defects, destroying the translational symmetry.

The calculated phonon frequencies (Table 9.47) are compared with the experimental Raman signal measured at room temperature in Fig. 9.29. According to group-theoretical analysis, [1023] phonon modes are expected at the Brillouin-zone center (Γ -point) for NiWO_4 at room temperature. Among them 18 even modes ($8A_g$ and $10B_g$) are Raman active. Note that the number of Raman-active modes is doubled in the AF2 state and quadrupled in the AF1 state (Fig. 9.29a) due to the symmetry lowering caused by the spin ordering. The results obtained in [994] suggest that phonon frequencies are very sensitive to the type of the functional used in the calculations. In particular, for the hybrid PBE0-type functional, composed of HF and DFT contributions, one can find this dependence by varying the HF-to-DFT ratio (Fig. 9.29b). The results for the NiWO_4 under consideration suggest that 13% HF admixture gives the best result for both lattice dynamics and the equilibrium structure.

One can compare the results for NiWO_4 with first-principles phonon calculations performed for other tungstates. Most previous works were based on the plane-wave DFT approach, which results in the underestimation of the high-frequency stretching W–O mode by ~ 45 cm^{-1} in ZnWO_4 [1031], ~ 32 cm^{-1} in CdWO_4 [1032], and ~ 52 cm^{-1} in CuWO_4 [1017] for the PBE Hamiltonian and by ~ 4 cm^{-1} in MgWO_4 [1033] for the simple LDA-type Hamiltonian. By contrast, the calculations [1013] using the hybrid PBE0 Hamiltonian with 25% HF admixture overestimated the frequencies of the stretching W–O modes by ~ 34 cm^{-1} in ZnWO_4 and ~ 39 cm^{-1} in CaWO_4 , which has the scheelite-type structure constructed of WO_4 tetrahedra and CaO_8 polyhedra. The calculations [994] suggest that a variation of the HF admixture to the DFT Hamiltonian systematically influences the values of phonon frequencies (Fig. 9.29b). The best agreement with the high-frequency stretching W–O mode in

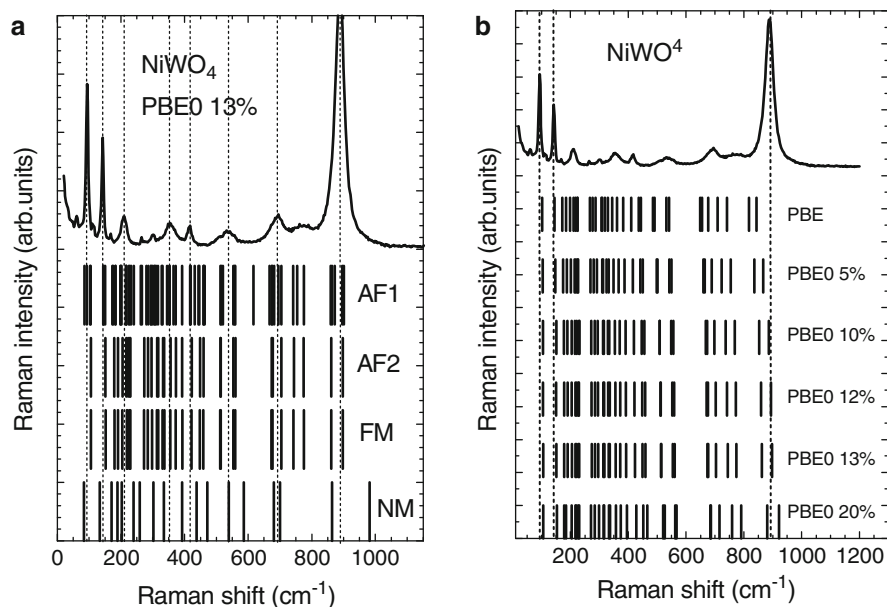
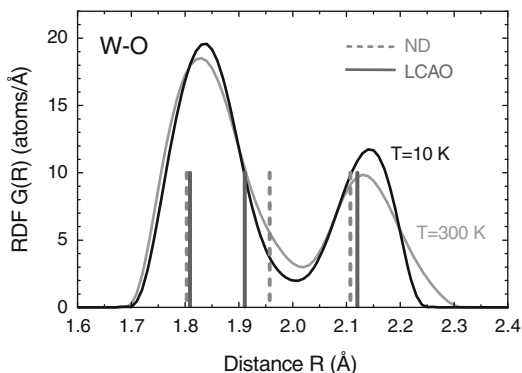


Fig. 9.29 (a) Comparison of the room-temperature experimental Raman spectrum for NiWO_4 with mode frequencies (vertical lines), calculated by the first-principles LCAO method using hybrid PBE0 13% HF Hamiltonian for AF1, AF2, FM, and NM states. (b) LCAO results for hybrid PBE0-type Hamiltonian with different percentages (0–20%) of HF contribution in the AF2 state)

NiWO_4 was found for 13% HF admixture, which results in the difference below 5 cm^{-1} (Table 9.47).

Finally, we would like to discuss the distortion of the metal–oxygen octahedra (Table 9.46). The LCAO calculations predict a larger distortion of the WO_6 octahedra but a weaker distortion of the NiO_6 octahedra compared to diffraction [1012]. In the AF1 state observed experimentally, the NiO_6 octahedra are nearly regular according to the LCAO results and have three slightly different pairs of the Ni–O bonds with the standard deviation of about $0.02 \text{ \AA}$. On the contrary, the LCAO results for the WO_6 octahedra predict three significantly different pairs of the W–O bonds with the standard deviation of about $0.13 \text{ \AA}$. The local distortion around metal atoms can be obtained experimentally by X-ray absorption spectroscopy (XAS), which is the local structural probe giving information complementary to what is given by the diffraction methods [933]. In Fig. 9.30, we show the results obtained by the W L_3 -edge XAS in NiWO_4 at 10 K and 300 K. The use of regularization-like method [1034, 1035] allowed the reconstruction of the radial distribution function (RDF) within the first coordination shell of tungsten (Fig. 9.30). The shape of the RDF unambiguously confirms the strong distortion of the WO_6 octahedra and shows a rather weak dependence on the temperature variation. Moreover, the comparison of the RDF with the lengths of the W–O bonds, obtained by LCAO method in [994] and by neutron diffraction in [1012], suggests that in the LCAO calculations the

Fig. 9.30 Comparison of the radial distribution functions (solid lines) for the first coordination shell around tungsten, obtained from the analysis of the W L_3 -edge EXAFS spectra at 10 K and 300 K, with the W–O bond lengths obtained by neutron diffraction (ND) in [1012] (dashed vertical lines) and LCAO calculation in the present work (solid vertical lines)



position of the middle group of the W–O distances at 1.911 Å is reproduced slightly better. In fact, the value obtained by the diffraction [1012] $R(\text{W–O1})=1.957$ Å is located in the valley region of the RDF. At the same time, the shortest and the longest W–O bonds are very close in LCAO and diffraction.

As we have seen in this chapter, the HF and DFT LCAO methods, implemented in the computer code CRYSTAL, present efficient computational schemes for the study of different properties of periodic systems. Real-solid properties in many cases depend on the point defects, destroying the translational symmetry. In the next chapter, we discuss the models used for defective crystals study and give examples of the LCAO calculations of defective crystals.

Chapter 10

Modeling and LCAO Calculations of Point Defects in Crystals

For a low defect concentration, it becomes appropriate to model a single point defect in the environment of the remaining solid. However, in the case of a solid solution, the single-defect model is not appropriate as the stoichiometry change is introduced by a regular substitution of the host-crystal atoms by those of other chemical species. In this case the periodic (supercell) point-defect model is more appropriate. We discuss the results of the LCAO calculations of different types of point defects in oxides: native point defects—an interstitial oxygen atom in a MgO crystal and a neutral oxygen vacancy (F-center) in corundum Al_2O_3 and SrTiO_3 crystals—substitution defects (vanadium-doped rutile TiO_2 crystal, iron impurity in the SrTiO_3 crystal). The calculations of the charged point defects are demonstrated by a charged oxygen vacancy (F^+ center) in a corundum Al_2O_3 crystal.

10.1 Symmetry and Models of Defective Crystals

10.1.1 Point Defects in Solids and Their Models

The theory of perfect crystalline solids explains those bulk properties of crystals that do not depend on boundary effects and other defects of the structure. However, real solids do not demonstrate translational symmetry. Boundaries and other regions of disruption of translational symmetry called defects are always present. Many practical applications of solids are based on the use of the properties caused by defects. By varying the defect structure of solids, it is possible to change their physical and chemical properties in such a way that the defective crystals find useful applications. As an example, we mention TiO_2 crystal that has been successfully applied as a semiconductor photocatalyst with high oxidizing power and high resistance to photo- and chemical corrosion. However, the relatively large bandgap (3 eV) does not permit efficient absorption of visible light and hence prevents TiO_2 from being used in large-scale environmental applications. Chemical doping of TiO_2

allows the bandgap to be reduced. The theoretical study of the doped TiO_2 helps to solve the important problem: how to best manipulate the gap while maintaining the beneficial photocatalytic properties [661].

The defects in solids can be classified according to the dimensions of the region of translation symmetry disruption. When one or a few nearest host-crystal sites are disturbed, we speak of *point* (zero-dimensional) defects, called also *local defects*. Also known are *extended defects* that introduce structural imperfections in lattice directions—*linear* (one-dimensional) defects or in the lattice planes (*planar* or two-dimensional defects). The surface of a crystal and dislocations are the important examples of two-dimensional and linear defects, respectively.

The point defects, in turn, are classified as *native* (intrinsic) and *substitution* defects. The intrinsic point defects appear as a *vacancy* (the absence of an atom in a crystal lattice position) or as an *interstitial* defect (the presence of the host-crystal atom in an interstitial position). The host-crystal atoms can be substituted for another atom of a different chemical species at a regular lattice site or at the interstitial position (impurity center or *substitution* defect). The point defects can also be classified as neutral and charged relative to the host-crystal lattice. The perturbation of a solid by the charged point defect includes the short-range (local) and long-range (Coulomb) parts. The former is reproduced in the calculations of the sufficiently small fragments of the defective crystal; the calculation of the latter requires special methods, taking into account the polarization of the surrounding crystal by the point defect.

In what follows, we consider, as examples, LCAO calculations of different types of point defects in oxides: native point defects—interstitial oxygen atom in MgO crystal and neutral oxygen vacancy (F-center) in corundum Al_2O_3 and SrTiO_3 crystals—substitution defects (vanadium-doped rutile TiO_2 crystal, iron impurity in SrTiO_3 crystal). The calculations of the charged point defects are demonstrated by a charged oxygen vacancy (F^+ center) in corundum Al_2O_3 crystal.

For low defect concentration, it becomes appropriate to model a single point defect in an environment of the remaining solid. In such a model, the translation symmetry is completely absent so that the crystal with a single point defect can be seen as a gigantic molecule. However, in the case of a solid solution, the single-defect model is not appropriate as the stoichiometry change is introduced by regular substitution of the host-crystal atoms by those of other chemical species. In this case, the periodic point-defect model is more appropriate. As an example, we discuss in Sect. 10.3 the modeling of $\text{Ba}_x\text{Sr}_{1-x}\text{TiO}_3$ solid solutions.

The calculation methods of quantum chemistry are widely applied to the point defects in solids. This application is made after the choice of one of the existing defective-crystal models (see Fig. 10.1).

If a single point defect is introduced into an otherwise perfect crystal, the translational symmetry is, in principle, lost completely (see Fig. 10.1), and equations should be solved for all atoms of the solid, *that is*, for the aperiodic system [284]. Obviously, the application of some kind of simplified model is desirable. In many cases the electronic states of defects in a crystal are localized in some relatively small region. The degree of this localization depends on the nature of the defect

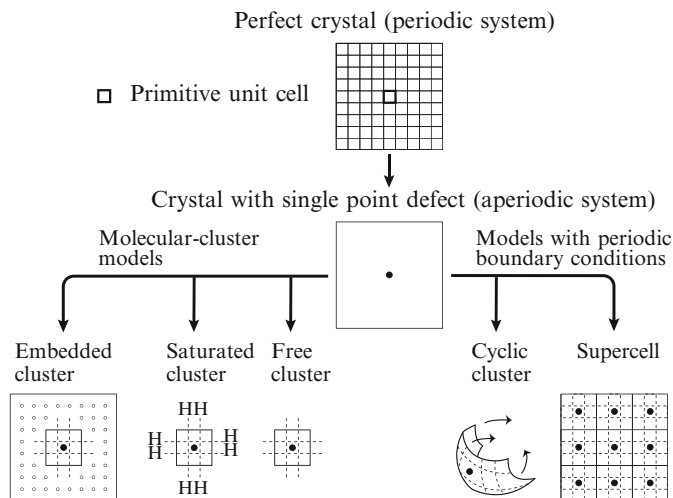


Fig. 10.1 Defective crystal models

and of the host crystal. The local nature of a single point defect allows a smaller piece of a crystal to be taken (called a *cluster*), but its size must be chosen in such a way that there is at least one shell of atoms between the defect zone and the cluster surface that remains undisturbed. The obvious way is to separate the part of the crystal perturbed by the defect from the still crystalline background and treat only the former in an explicit manner. On the one hand, the need for economizing calls for a model consisting of as few atoms as possible. On the other, the explicitly treated part of the crystal should, in principle, extend far enough for the effect of the defect to become negligible [284]. This means, up to the point where the amplitude of the localized wavefunctions, the deviations of charge density and of host-atom positions relative to the unperturbed case become close to zero. In practice, this is assumed to be for a group of atoms around the defect (cluster). The three criteria above are almost never satisfied to a necessary degree with clusters that can be squeezed into the computer. Therefore, at least some kind of convergence test in all three respects is proper.

The electronic structure of the molecular cluster can be calculated using any of the methods developed for the molecules. However, the problem arises at the molecular-cluster surface, *that is*, with the representation of the rest of the crystal. As is shown schematically in Fig. 10.1, there are different possibilities for this representation. In *molecular-cluster* models the group of atoms chosen is embedded into the crystalline environment (*embedded-cluster* model), or the cluster surface atoms are saturated by hydrogen or other species atoms (*saturated-cluster* model). In the most crude model, the free cluster (neutral or charged) is chosen.

The models with periodic boundary conditions (*the supercell* and *the cyclic-cluster* models) allow calculation of the one-electron states of perfect and defective crystals at the same level of approximation. The supercell model (SCM) and

cyclic-cluster model (CCM) have both similarities and discrepancies. One similarity is that in both models not a standard primitive unit cell but an *extended* unit cell (supercell or large unit cell) is considered. The discrepancy is that the periodic boundary conditions in the SCM are introduced for the infinite crystal or its main region, but in the CCM model—for the extended unit cell itself.

The calculation schemes usually used for point defect include (1.) the choice of the *model* of the defective crystal, (2.) the choice of the *Hamiltonian* (Hartree–Fock, DFT or hybrid, semiempirical), (3.) the choice of the *basis* for the one-electron Bloch functions decomposition—linear combination of atomic orbitals (LCAO) or plane waves (PW).

SCM is used as a rule for the neutral-point-defect calculations (for the charged point defects, the field of periodically repeated charge has to be suppressed in one or another way). The molecular- and cyclic-cluster models are more universal as they can be applied both for the neutral and charged point defects.

In the SCM the calculations with HF or hybrid Hamiltonians are made in the LCAO approximation; DFT Hamiltonians are used both in the LCAO and PW representations. CCM can be practically realized with the semiempirical LCAO Hamiltonians.

In SCM we let the defects be situated periodically and try to make the separation between defects as large as possible. If the extended unit cell is large enough, the defects are separated by large distances and do not affect each other's electron structure so that the results of the application of SCM and CCM models become close. The bandwidth of defect states depends primarily on the degree of overlap of the functions describing the defect electron states from different supercells and decreases rapidly with increasing defect period. Therefore, this bandwidth can be used as the criterion of the convergence of the SCM results to those of CCM. The cyclic-cluster model is conceptually a supercell-type approach but is technically more closely related to the simple molecular-cluster model. SCM introduces the artificial point-defect periodicity; CCM describes the single point defect.

All the approaches to the theoretical description of defective crystals use information about the symmetry of the system or its model. As mentioned above, a single defect embedded in a crystal disrupts the translational symmetry of a perfect crystal so that it may be considered as a gigantic molecule with a point-symmetry group inherent to molecules. There are two cases: an *atomic type* point defect, which occupies one point of a crystal lattice or an interstitial position and can be a substitutional impurity, vacancy, or interstitial atom; and a *molecular-type* point defect, which occupies several atomic or interstitial points of a crystal lattice and can be composed of an impurity molecule or a cluster of several vacancies at neighboring lattice points. In the first case, the symmetry group of the defect crystal is fully determined by the site symmetry of the point $\mathbf{q}$ where the atomic defect appears. In a crystal with a symmorphic space group, the atomic defect may occupy the position $\mathbf{q}$ with the symmetry of the crystal class or one of its subgroups. In nonsymmorphic crystals, the point group of the crystal with a single point defect of atomic type is always a subgroup of the crystal class. In a crystal with point defects of molecular type, the center of the impurity molecule is situated at a point

with some site symmetry. A molecular defect has its own point symmetry so that the point symmetry of the whole system is determined by the common elements of two groups: the point group of the isolated molecule and the site-symmetry group of the site where the impurity molecule is situated. However, it is necessary to also take into account the orientation of the impurity molecule with respect to the crystal symmetry axes.

It can be assumed that when a point defect appears, the configuration of the crystal matrix around the defect does not change (the model of a rigid lattice). In reality, this assumption is approximately correct only for some point defects and as a rule only for the ground electron state. Excitation of the defect electrons causes significant reconstruction of the defect's surroundings so that the point symmetry of the entire system may change. In many calculations, the distortion of the crystal lattice by a defect is at first neglected. Then, this distortion is taken into account with approximate wavefunctions obtained for the rigid-lattice model. Therefore, initially, the symmetry is approximated in the framework of the rigid-lattice model. The knowledge of the actual symmetry of a crystal with a point defect is necessary for correct understanding of all its properties: the symmetry determines the selection rules for optical transitions in the defect, the symmetry and the splitting of local energy levels in external fields, and the features of EPR and NMR spectra, *etc.*

To understand the nature of a point defect in a crystal and the degree of its influence on the properties of the crystal matrix, it is necessary to relate the local energy levels of the defect to the energy-band structure of the perfect crystal. But these two systems (crystal with defect and perfect crystal) have different symmetries, and the classification of electron states is made according to irreps of either a point group (for a crystal with a single defect) or a space group (for a perfect crystal).

In the molecular-cluster model it is rather easy to establish the relationship between energy levels and one-electron states of a molecular cluster with and without a point defect. The symmetries of both systems are described either by the same point group or by a point group that is a subgroup of the other (in the case of a molecular-type defect). Hence, in the cluster model, the relationship between the classification schemes of electron energy levels and states of perfect and imperfect crystals is simple. But the relationship between the cluster electron energy structure and that of a perfect crystal is much more complicated. In the models using PBC, the application of the site-symmetry approach is quite useful [13]. The single-defect localized electron states of a given energy level span the space of an irrep of defect point-symmetry group F_D . The band states of a perfect crystal are classified according to irreps of the space group G . It is useful to determine which band and localized states are allowed by symmetry to mix (*e.g.*, for calculating the electron structure from atomic basis functions). We consider the appearance of a point defect as a perturbation of a perfect crystal. According to perturbation theory, only states with the same symmetry may interact with one another. The common symmetry group of both systems is $F_D \subset G$. Let β be an irrep of F_D that describes one of the defect states. To establish the possibility of its mixing with the perfect crystal states of symmetry $D^{(**k\gamma)}$, it is sufficient to know whether

the restriction $D^{(*k\gamma)} \downarrow F_D$ contains the irrep β . If the state of symmetry $D^{(*k_0\gamma)}$ does not contain the state of symmetry β , then the contribution of the states with k near k_0 is small according to the perturbation theory, although it is not equal to zero due to the symmetry. As an example, let us consider the s -states of an impurity at a cation site (Wyckoff position a , site group D_{2h} , s -state has symmetry a_g) or at an anion site (Wyckoff position f , site group C_{2v} , s -state has symmetry a_1) in rutile TiO_2 . From band calculations, we know the symmetry of states on the boundaries of the forbidden gap in a rutile TiO_2 crystal (see Chap. 9): Γ_1^+ (the bottom of the lowest conduction band) and Γ_3^+ (the top of the highest valence band). From the table of induced representations of the space group D_{4h}^{14} , we find $\Gamma_1^+ \downarrow D_{2h}^{(a)} = a_g$; $\Gamma_3^+ \downarrow D_{2h}^{(a)} = b_{1g}$, that is, the s -states of an impurity may mix with the states of the bottom of the lowest conduction band, but not with the states of the top of the uppermost valence band. The anion site is at the Wyckoff position f ($F_f = C_{2v}$). We get $\Gamma_1^+ \downarrow C_{2v}^{(f)} = a_1$; $\Gamma_3^+ \downarrow C_{2v}^{(f)} = b_2$, that is, the s -states of an impurity at an anion site may mix with the states of the bottom of the lowest conduction band but not with the states of the top of the uppermost valence band. From this consideration, it follows that the defect local levels due to the s -states of the impurity both at Ti and O sites split from the conduction-band bottom. Such information is useful for the study of doping influence on the rutile crystal bulk properties.

In the next sections we consider in more detail the defective-crystal models mentioned above.

10.1.2 Symmetry of Supercell Model of Defective Crystals

The recent trends in the theory of the point defects in solids and of the crystalline surfaces, formally aperiodic systems, are connected with the widespread application of periodic boundary conditions (PBC) and computer codes developed for the perfect crystals, see [552, 662, 663] and references therein. This allows one to use the same numerical schemes both for the host and defective crystal to study changes induced by a point defect or surface: additional local energy levels in the optical gap, lattice relaxation around defects, *etc.* As was noted above, in the theory of point defects, two models with PBC are used: the supercell model (SCM) and the cyclic-cluster model (CCM).

The application of the supercell model to the defective crystals requires consideration of periodic systems with a sufficiently large number of atoms in the unit cell. The possibilities of the supercell model extend if the full symmetry of the object is taken into consideration. It was demonstrated [665–667] that the study of the symmetry of a crystal with a periodic defect permits, in some cases, investigation of the dependence of the results of electronic-structure calculations on the period of a defect by only changing the symmetry of the system without any augmentation of the supercell. The symmetry of the crystal with a periodic defect is determined by the site symmetry of the defect in the crystal and by the symmetry of the host-crystal matrix. Let a point defect (impurity atom or molecule, one or a few vacancies)

occupy a position $\mathbf{q}$ in a perfect crystal with a space group G (crystal class F). A site-symmetry group of the defect in the crystal S_D consists of common elements of two groups: of the symmetry group $S_D^{(0)}$ of the defect itself and the site-symmetry group S_q of the position $\mathbf{q}$ in the crystal occupied by the defect. The group S_D depends on the mutual orientation of the symmetry elements of the groups $S_D^{(0)}$ and S_q .

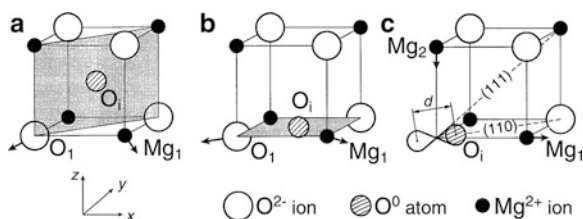
Let us consider now a periodic structure that arises in the supercell model when the embedded defect is periodically repeated and occupies in this structure some position $\mathbf{Q}$ with site-symmetry group $S_Q = S_D$. The symmetry of the obtained periodic structure is characterized by some space group G_D . One seeks for all the possible space groups $G_D = T_A F_D$ of the defective crystal for a given host crystal (space group G) and for a given point defect in the crystal (point group S_D). Here, translation group T_A includes translations $\mathbf{A}$ of the supercell. Some symmetry operations disappear when one goes from the space group G to the space group G_D . Therefore, the group G_D has to be a subgroup of $G_D \subseteq G$ with a crystal class satisfying the condition $S_D \subseteq F_D \subseteq F$. The possible space groups G_D of the crystal class F_D are those that have the group S_D as a site-symmetry subgroup. In this way, one obtains the list of space groups G_D that may describe the symmetry of the supercell model of a defective crystal for a given site symmetry S_D of the embedded defect and space group G of a host crystal.

In the framework of the same space group G_D , the periodical structures may differ by the length of supercell basic translation vectors $\mathbf{A}_1, \mathbf{A}_2$, and $\mathbf{A}_3$ for the same type of Bravais lattice. These vectors have a definite orientation with respect to the symmetry elements of the group G_D , and sometimes there is a definite relation between their lengths. In addition, they have to be integer linear combinations, see (4.77), of basic translation vectors of the host perfect crystal. This combination defines the transformation matrix l with the determinant L (the number of primitive unit cells in the supercell). As was noted, this transformation is called a symmetric one if the point symmetry of the Bravais lattice of supercells is the same as that of the host-crystal Bravais lattice, see Chap. 4. Use of the symmetric transformation for the supercell generation allows the point symmetry of the defective crystal in the supercell model to be maintained as high as possible. These conditions determine the matrix l , *that is*, the translational subgroup T_A of the symmetry group G_D . Finally, it is necessary to verify whether the obtained group G_D is a subgroup of the symmetry group of the host crystal. This condition assures that all the atoms of the system transform into themselves under the operations of the group G_D . If $\tilde{G}_D \subset G$, then $G_D = \tilde{G}_D$; if $G_D \not\subset G$, then the group $\tilde{G}_D$ has to be excluded from the list of the possible groups G_D .

Finally, the generation of the possible space groups with a periodical defect in the supercell model consists of the following steps [667]:

(a) determination of the site group S_D of the defect in the crystal, (b) determination of the crystal classes satisfying the condition $S_D \subseteq F_D \subseteq F$, (c) determination in the space groups of these classes those that have the site-symmetry subgroups S_D , (d) generation of the matrix l and the supercell translation vectors $\mathbf{A}_i$ by symmetric transformation of the host-crystal basic translations, and (e) verification of the condition $G_D \subseteq G$.

Fig. 10.2 Configurations of the interstitial oxygen atom in MgO



The groups G_D of a supercell model with one point defect for a supercell are symmorphic; they belong to the crystal class $F_D = S_D$ with all the types of crystal lattices possible for this crystal class. The point symmetry of the cyclic cluster coincides for the host crystal—with the point-symmetry group F , for the defective crystal—with the point-symmetry group S_D .

Let us consider some examples. In MgO crystal, the supercells, containing 8, 16, and 32 atoms (S8, S16, S32), are obtained by a linear symmetric transformation of the fcc lattice basic translation vectors with matrices

$$l^{(4)} = \begin{pmatrix} 1 & 1 & -1 \\ 1 & -1 & 1 \\ -1 & 1 & 1 \end{pmatrix}, \quad l^{(8)} = \begin{pmatrix} 2 & 0 & 0 \\ 0 & 2 & 0 \\ 0 & 0 & 2 \end{pmatrix}, \quad l^{(16)} = \begin{pmatrix} 3 & -1 & -1 \\ -1 & 3 & -1 \\ -1 & -1 & 3 \end{pmatrix}$$

Superscript (n) in $l^{(n)}$ denotes the number of primitive unit cells in the supercell. The supercell translation vectors for A_1 , A_2 , and A_3 for $l^{(4)}$, $l^{(8)}$, $l^{(16)}$ correspond to simple cubic, face-centered-cubic, and body-centered-cubic lattices, respectively. The host crystals, consisting of the corresponding supercells, have the symmetry of cubic space groups O_h^1 , O_h^5 , and O_h^9 , respectively. For the isoelectronic Be, Ca impurities in the Mg site, the site-symmetry group coincides with the point-symmetry group of the host crystal, *that is*, the space groups of the defective crystals are the same as for the host crystal. The Li impurity atom is displaced from the Mg site along the fourth-order symmetry axis (the Li atom site symmetry is C_{4v}). As a result, the space groups of the defective crystal are now tetragonal— $C_{4v}^{(1)}$, $C_{4v}^{(9)}$, and $C_{4v}^{(9)}$, respectively (the face-centered lattice is absent in the tetragonal system).

An additional neutral interstitial oxygen O_i atom as a point defect in MgO crystal can have several configurations. In three of these (called v , f , and e), the oxygen atom is at the volume, face, or edge centers, respectively, of the cubic unit cell. Figure 10.2 shows volume-(a), face-(b) centered configurations, and a (110)-oriented dumbbell (see below) configuration (c). The point symmetry of the v , f , and e configurations is T_d , D_{2h} , and C_{4v} , respectively. The space groups for MgO with these centers in the supercell model depend on the supercell chosen, and they are given in Table 10.1. The other three configurations vd , fd , and ed are so-called dumbbell-shaped defects formed when the O_i is moved toward a nearest-neighbor O^{2-} lattice anion along $\langle 111 \rangle$, $\langle 110 \rangle$, or $\langle 001 \rangle$ directions, respectively, the lattice anion being simultaneously displaced from its site along the same direction. The center of the dumbbell is at the lattice site, and the point symmetry of these

Table 10.1 Space-group symmetry for the supercell model of an oxygen-atom interstitial O_i in MgO crystal [666]

Center	F_D	Supercells		
		$I^{(4)}$	$I^{(8)}$	$I^{(16)}$
v	T_d	$T_d^1(215)$	$T_d^2(216)$	$T_d^3(217)$
f	D_{2h}	$D_{2h}^{19}(65)$	$D_{2h}^{25}(71)$	$D_{2h}^{25}(71)$
e	C_{4v}	$C_{4v}^1(99)$	$C_{4v}^9(107)$	$C_{4v}^9(107)$
vd	D_{3d}	$D_{3d}^5(166)$	$D_{3d}^5(166)$	$D_{3d}^5(166)$
fd	D_{2h}	$D_{2h}^{19}(65)$	$D_{2h}^{25}(71)$	$D_{2h}^{23}(69)$
ed	D_{4h}	$D_{4h}^1(123)$	$D_{4h}^{17}(139)$	$D_{4h}^{17}(139)$

defects is D_{3d} , D_{2h} , and D_{4h} , respectively. The space groups of MgO containing these defects are given in the last three lines of Table 10.1. The results of Table 10.1 were obtained using the list of subgroups of the space groups given on the Internet site www.cryst.ehu.es. For example, the supercell transformation with the matrix $I^{(4)}$ changes the host-crystal space group from O_h^5 to O_h^1 . Choosing from the list of subgroups of space group O_h^1 those symmorphic subgroups that refer to the crystal class T_d (point symmetry of the v configuration), we obtain directly the result given in the third column of Table 10.1.

The next example—the impurity atom on the Ti site of rutile structure with the space group D_{4h}^{14} . There are two titanium atoms in the primitive unit cell, occupying the two-site Wyckoff position a with coordinates (000) and $(\frac{1}{2}\frac{1}{2}\frac{1}{2})$. An impurity atom replaces a Ti atom with the site symmetry D_{2h} . Therefore, the space group of the defective crystal belongs to the crystal class D_{2h} . Four possible symmetric supercell transformations for the space group D_{4h}^{14} are given in Table 6.3. The first of them maintains the simple tetragonal lattice of the host crystal; the other three transform it to the body-centered tetragonal lattice. Respectively, the possible symmetry groups of the defective crystal are the following: D_{2h}^1 , D_{2h}^{19} , D_{2h}^{23} , and D_{2h}^{25} .

In the Ti atom site-symmetry group, two of three second-order axes are directed along the diagonals of the square, see Chap. 2. In the standard setting of the space groups with D_{2h} point symmetry, all the three second-order axes are directed along the Cartesian coordinate axes. This difference must be taken into account [667].

The point symmetry of the cyclic-cluster model coincides with point groups F and F_D for the host and defective crystal.

10.1.3 Supercell and Cyclic-Cluster Models of Neutral and Charged Point Defects

In the point-defect calculations there are two criteria to be met: the model used for solving the quantum-mechanical problem has to describe sufficiently well both (a) the extended crystalline states and (b) the localized states of a single point defect.

The CCM can be defined from the two points of view: it can be regarded either as the application of the Born–von Karman cyclic boundary conditions directly to the large unit cell (supercell) or as the band-structure calculation on SCM with (A) applying the $\mathbf{k} = \mathbf{0}$ approximation and (B) neglecting interactions beyond the Wigner–Seitz cell corresponding to the supercell chosen. The SCM have no restrictions like A and B and thus CCM could be considered as a special approximation to the SCM.

The economic approach to a single-point-defect study in a model with PBC consists of three stages [664].

In stage 1 the band-structure calculation of a perfect crystal is performed, in order to fix the shape and size of the supercell that reasonably models the host crystal, *that is*, when the above-described condition (a) is met. These calculations are made using a primitive unit cell and $\mathbf{k}$ -sampling in the usual (primitive) BZ.

The one-to-one correspondence was demonstrated between a fixed $\mathbf{k}$ -mesh and the supercell in a real space, see Eqs. (4.77), (4.80), and (4.84). Due to the one-to-one correspondence between $\mathbf{k}$ -point sampling and the supercell size in a real space, it is possible to find such a $\mathbf{k}$ -mesh that ensures a compromise between its size and a reasonable reproduction of the total- and one-electron energies, as well as the electron-density distribution in the host crystal. At this stage, the $\mathbf{k}$ -point sets satisfying (4.84) are used.

In stage 2, the calculations are made for a defective crystal using SCM, in order to check the above-described criterion (b). It is reasonable to begin from the smallest supercell, chosen at stage 1, *that is*, corresponding to the converged results of the band calculations. The supercell shape should be such as to exploit the point symmetry of the defect as far as possible. In the particular case of the cubic SrTiO₃ crystal, cubic supercell of 80 atoms ($L = 2 \times 2 \times 2$, the diagonal matrix $\mathbf{I}$ in transformation (4.77) is taken) may be used for a perfect crystal in the HF calculations but larger supercells are necessary in the DFT–PWGGA calculations [664]. When estimating the defect–defect interaction from the calculated defect bandwidth in the second stage, one makes a decision about the need for a further increase of the supercell. In particular, the Fe impurity at the Ti site bandwidth in the HF calculations still changes when the supercell is increased from 80 to 160 atoms [664]. This means that the local states induced by the point defect are sufficiently well localized only in the larger, 160-atom supercell [664]. That is, in stage 2, the comparison of supercell results for different $\mathbf{k}$ -meshes allows us to decide if it is necessary to further increase a supercell, in order to surpass artificial defect–defect interaction. When energies at $\mathbf{k} = \mathbf{0}$ and nonzero, $\mathbf{k}$ supercell calculations turn out to be close; this means that the corresponding cyclic cluster is appropriate for the single-point-defect study as CCM corresponds to the Γ point only consideration for the supercell chosen.

In the most time-consuming stage 3, the CCM is used (*i.e.*, the band-structure calculations for the chosen supercell are performed only at $\mathbf{k} = \mathbf{0}$) for the determination of the equilibrium geometry, *that is*, relaxation of the crystalline lattice around the point defect and calculation of other defective crystal properties.

As is seen, the approach described combines both supercell and cyclic-cluster models of the defective crystal and differs from the traditional supercell calculations

by an attempt to exclude in stage 3 the spurious point-defect periodicity. This exclusion allows us formally to escape periodic repeating of the crystalline lattice relaxation around the point defect. Furthermore, the different charge states of the point defect could be also considered in stage 3 without principal difficulties since in CCM the charge is not periodically repeated over the lattice.

The defect-formation energy is an important property of the defective crystal. The formation energy ΔE_f of a neutral defect in CCM is given by

$$\Delta E_f = E_d - E_B + E_R - E_A \quad (10.1)$$

where E_B is the bulk-crystal total energy, E_d is the total energy of the cyclic cluster with the point defect, and E_A and E_R the energies of the added and removed species, respectively. The bulk-crystal energy $E_B = LE^{(0)}$, where L is the number of primitive cells in the cyclic cluster and $E^{(0)}$ is the energy per primitive cell. As an example, for ionic MgO crystal, the formation energy of X substitution impurities (X=Ca, Be substitutes Mg atom) [668] can be given in terms of the isolated atoms or isolated ions

$$\Delta E_X^L = E_{\text{MgO-X}} - LE_{\text{MgO}}^{(0)} + E_{\text{Mg}^{2+}} - E_{\text{X}^{2+}} \quad (10.2)$$

$$\Delta E_X^L = E_{\text{MgO-X}} - LE_{\text{MgO}}^{(0)} + E_{\text{Mg}} - E_X \quad (10.3)$$

When the relaxation is taken into account (shifting of some nuclei around a defect from a reference bulk-crystal situation), the total energy E_d is corrected by the relaxation energy E_{rel} .

The oxygen-removal energy for MgO crystal ΔE_f (formation energy of neutral oxygen vacancy, also called an F center) is defined as the energy of the system, containing the F center, plus the energy of an isolated oxygen atom minus the energy of the perfect crystal [669]. In the LCAO approximation, the energies of added or removed atoms are calculated in the same numerical scheme that is used for the bulk and defective crystal calculation (the atomic basis is used that is appropriate for a free atom, see Chap. 9). In PW calculations, the energy of the isolated atom is obtained by calculations on a number of periodic systems, containing one atom per increasing supercells, and the final size of the supercell is taken large enough to ensure that the interaction between atoms introduces a sufficiently small error (this error was 0.01 eV in calculations [669]). Within the supercell approach, ΔE_f should tend to a well-defined limit with increasing supercell size. For a defect to be considered as single, sufficiently large supercells must be adopted to avoid spurious interactions among neighboring defects.

In the SCM (CCM) models two finite energies are compared when determining the defect-formation energy: they are the total energies per unit supercell of the two crystals (perfect and defective). In view of the large energies involved, it is important that the same cell be used for the perfect and defective crystals to ensure cancelation of errors.

Table 10.2 Ca and Be HF substitutional energies ΔE_f (in eV) in MgO as a function of the size of the supercell. M is the number of atoms in the supercell; ΔR is the variation (in Å) of the distance between the defect and its first (6O) and second (12Mg) [668]

M	Ca			Be		
	ΔE_f	ΔR		ΔE_f	ΔR	
		First(6O)	Second(12Mg)		First(6O)	Second(12Mg)
8	7.20	–	–	–3.81	–	–
16	7.12	–	–	–3.80	–	–
32	7.09	–	–	–3.83	–	–
16	6.56	0.073	–	–3.93	–0.044	–
32	6.43	0.084	–	–4.00	–0.053	–
32	6.25	0.097	0.031	–4.10	–0.070	–0.022

As an example, we consider the convergence of the LCAO–HF AE supercell calculations of Ca and Ba atom substitution in bulk MgO, the details of the computational scheme used can be found in [668]. In Table 10.2, the substitution energies are given as a function of the supercell size for nonrelaxed and relaxed defective lattice. The supercells of 8, 16, and 32 atoms correspond to the host-crystal fcc lattice vector transformations, giving simple, face-centered, and body-centered cubic lattices of supercells with $L = 4, 8$, and 16 (8, 16, and 32 atoms), respectively (see Sect. 10.1.2). Table 10.2 shows that in an unrelaxed lattice, the increasing of the supercell from 8 to 32 atoms changes the defect-formation energy from 0.11 eV (Ca substitution) and 0.02 eV (Be substitution). It is also seen that for the largest supercell, the Ca substitutional energy reduces from 7.09 to 6.43 eV when the first star of neighbors (six O ions) is allowed to relax; a further energy gain of 0.19 eV is obtained after allowing the second neighbors (12 Mg ions) to relax, the total relaxation energy, 0.84 eV, being substantial. In the case of the Be substitution, the relaxation energy, 0.27 eV, is considerably smaller. In the Be case, the displacements are smaller and in the opposite direction to those for the Ca substitution, but the pattern is otherwise qualitatively similar. Thus, quite small unit cells appear to be able to describe the effect of electronic rearrangement. In contrast, Table 10.2 indicates that nuclear-positional relaxation is much more long ranged, at least for fully ionic compounds such as MgO.

The dependence of the defect-calculation results on the supercell size in MgO was obtained for oxygen-atom removal energies in DFT–PW calculations [669]: increasing of the supercell from 8 to 64 atoms changed the defect-formation energy from 10.656 to 10.568 eV in unrelaxed lattice and from 10.553 to 10.547 eV for the relaxed lattice. In this case, the effect of relaxation appeared to be completely negligible.

The convergence of the results with the supercell size is strongly dependent on the point-defect nature. Ca and Be substitutions of Mg atom in MgO are examples of isoelectronic substitution, giving small impurity-atom displacement from the substituted atom site. However, in the case of the MO : X point defect ($M = \text{Mg, Ca, Sr}$; $X = \text{H, Li, Na, K}$), this displacement becomes large due the difference between the host and substitution atoms. The difference in the number of valence

electrons in M and X atoms (two and one, respectively) is called hole trapping. Ionizing radiation produces a variety of trapped-hole centers in metal oxides, both alkaline-earth oxides and perovskite-type compounds.

As a result of the impurity-atom displacement, the point defect in MgO has axial symmetry along one of the fourth-order symmetry axes of the cubic lattice. This lowering of the crystalline symmetry from cubic to tetragonal generates a dipole moment within the cell. A long-range dipolar defect-defect interaction then originates among defects in neighboring cells, and larger supercells are needed to obtain the converged results. As an example, the defect-formation energy of the MgO : Li center in UHF calculation's (for the Li only relaxation taken into account) changes with the supercell increase are the following [552]: 4.82 eV (8), 4.99 eV (16), 5.06 eV (32), and 5.10 eV (64). Here, the number of atoms in the supercell is given in brackets. When all the atoms in the supercell are allowed to relax, the defect-formation energy changes (in the calculations of the largest supercell of 64 atoms) from 5.43 eV (unrelaxed) to 4.15 eV (fully relaxed). The comparison with the data given in Table 10.2 demonstrates that for the hole-trapping center the convergence is slower than for isoelectronic substitution, and the geometry optimization plays a crucial role for the hole-trapping center: the difference in the defect-formation energy for fully relaxed and nonrelaxed largest supercells is 0.84 eV (Ca substitution), 0.27 eV (Be substitution), and 1.28 eV for the hole-trapping center. The atomic relaxations themselves are especially large for the Li atom (about 0.3 Å). It was found [552] that in the fully relaxed case, the convergence of the defect-formation energy is much faster (0.03 eV in going from a supercell of 8 atoms to one of 64 atoms) that shows that structural relaxation is an effective mechanism to screen and minimize long-range electrostatic interactions induced by the dipolar nature of the defect center.

When the alkali-metal ion replaces an alkaline-earth cation, it relaxes from the perfect lattice position toward the oxygen ion (O2) along the axial direction, which brings a formal +2 charge; the electron hole localizes at the opposite oxygen (O1), which in turn relaxes away from the X monovalent ion. However, this relaxation is periodically repeated, and it would be desirable to compare its role for the supercell calculations at the center and symmetry points of the BZ.

The supercell calculations give important information concerning the charge redistribution in the defective crystal. In particular, the UHF electronic structure of the trapped-hole defect MgO : [Li]⁰ indicates the localization of the unpaired electron at the O1 atom [552]. However, the degree of localization is quantified by the spin moment of O1 and changes significantly when different Hamiltonians are considered: the spin moment decreases from 0.98 at the UHF level to 0.41 for B3LYP and to about 0.1 with other DFT Hamiltonians [552]. The different degree of localization produced by DFT methods has important consequences for the atomic relaxation. Magnetic coupling constants determined by EPR and ENDOR techniques permit a direct comparison with experimental data to be made. In the particular case of the Li defect, the agreement is reasonable for the UHF result, where the hole is localized at O1. For the other Hamiltonians, the disagreement increases in parallel with the delocalization of the hole [552].

In PW calculations of defective crystals the use of PBC is the only possibility in the model choice. Apart from the problem of getting rid of interactions between defects by considering sufficiently large cells or by introducing corrections by averaging over the sampled k -points [670], the supercell technique seems to provide a natural “universal” reference for the neutral-point defects in crystals: the two structures that are compared satisfy the same boundary conditions, and the two wavefunctions (or density matrices) differ only in the vicinity of the defect in each supercell [671]. This is, however, no longer true when charged defects are considered. The artificial long-range Coulomb interactions between the periodic charged defect images introduce the divergence in the energy. The problem of the neutrality of the periodic array of charged defects is solved by superimposing a neutralizing charge uniformly spread in each supercell (a uniform, neutralizing “jellium” background charge is introduced to restore the electroneutrality of the unit cell).

It is also necessary to correct the defect-formation energy using an estimate of the dielectric response of the host system to the periodic ensemble of neutralized defects. While the self-energy of this charge becomes vanishingly small with increasing supercell size, this is not true for its interaction with the host crystal. Polarization of the crystalline medium by the local charge could be taken into account by allowing full relaxation of nuclear positions with very large supercell sizes. This is impossible in practice, and the corresponding finite contribution to the stabilization of the defect must be evaluated separately. With “reasonable” supercell sizes, it is necessary to correct for the interaction between charged defects. This correction can be performed classically using the experimental ϵ static dielectric constant [672]. However, using the experimental ϵ value makes the model inconsistent, not only because of the semiempirical character of this assumption, but also because use of the static dielectric constant would imply full relaxation of electrons and nuclei in the field of the defect charge, while use of the optical dielectric constant would require that no nuclear relaxation takes place [671]. To calculate the charged point-defect formation energy in SCM, some other correction schemes are suggested, [673–676]. These schemes were applied for the supercell calculations of point defects in semiconductors: tetrahedral—Si [674], diamond [677], InP [676], SiC [675] and hexagonal—AlN [678], GaN [679].

LCAO calculations of the charged point defects in metal oxides are made mainly in the molecular-cluster model, considered in the next section. As we already noted, PW molecular-cluster calculations are impossible as use of the PW basis requires the periodicity of the structure under consideration.

10.1.4 Molecular-Cluster Models of Defective Solids

The molecular-cluster model (MCM) of the defective crystal is the simplest and most direct approach. As was already noted, MCM is obtained by cutting out in the crystal some fraction of atoms consisting of the point defect and several spheres

of nearest neighbors, followed by an embedding of this cluster into the field of the surrounding crystal and (or) by saturating with the pseudoatoms the dangling bonds on the cluster surface. The embedding pseudopotential can also be used (see Sect. 8.2.3).

The main attractive features of a cluster model are the following: the simplicity of the mathematical formulation; the possibility of direct transfer of computational schemes, worked out in quantum chemistry of molecules; and applicability to almost all types of solids and point defects in them. A reasonable choice of cluster is possible when well-localized point defects are considered [680].

There are well-known [284] difficulties of the cluster model connected with changes of host-crystal symmetry, pseudoatom choice at the cluster boundaries, and the necessity to consider nonstoichiometric (charged) clusters. The validity of the results obtained within the cluster approach is often questionable due to some serious drawbacks: the strong unpredictable influence of the cluster shape and size on the results of calculations, the difficulties arising when relating the cluster one-electron energy levels with the band energies of the perfect crystal, and the appearance of “pseudosurface” states in the one-electron energy spectrum of the cluster. The appearance of the “pseudosurface” states is accompanied by the unrealistic distortion of electronic density on the cluster boundaries and can lead to artifactual resonances between the “pseudosurface” and the point-defect one-electron states.

In order to make the cluster model more realistic, a large number of embedding schemes have been developed. Most of them are oriented on special types of crystal (ionic, simple covalent) or are based on the use of special approximations in the Hamiltonian operator (local exchange, tight-binding approximations). The other group of cluster models is based on adding the effective-potential operator (the embedding operator) to the unperturbed-cluster Hartree–Fock operator, giving the proper one-electron solution for the perfect crystal. When the cluster shape and size are chosen, this embedding operator can be determined and used in the following perturbed-cluster calculations. This so-called embedded-cluster approach is sufficiently general and can be applied to different types of solids.

The only characteristic that to a certain extent depends on the nature of the solid, and local center in it is the minimal appropriate cluster size. This size is limited by the extent of localization of one-electron states in the perturbed and nonperturbed solid. At the same time, the extent of the defect-potential localization is not so critical if the cluster is chosen in such a way that the long-range polarization outside the cluster can be taken into account.

The use of *localized orbitals* for the cluster calculation is an efficient approach for defective crystals. To connect the perfect crystal localized orbitals and molecular-cluster one-electron states, the molecular cluster having the shape of a supercell was considered [683]. Such a cluster differs from the cyclic cluster by the absence of PBC introduction for the one-electron states. Evidently, the molecular cluster chosen is neutral and stoichiometric, but its point symmetry can be lower than that of the cyclic cluster. Let the localized orthogonal crystalline orbitals (Wannier functions) be defined for the infinite crystal composed of supercells. The corresponding BZ

is L times reduced (the supercell is supposed to consist of L primitive unit cells). The Wannier functions $W_n(\mathbf{r} - \mathbf{A}_l)$ are now introduced for the supercells with the translation vectors and satisfy the following equation:

$$\hat{H} W_n(\mathbf{r} - \mathbf{A}_l) = \sum_{\mathbf{A}_l} \varepsilon_n(\mathbf{A}_l - \mathbf{A}_l) \quad (10.4)$$

Here, $\hat{H}$ is the one-electron Hamiltonian of the crystal,

$$\varepsilon_n(\mathbf{A}_l) = \frac{1}{\sqrt{N}} \sum_{\mathbf{k}'} E_n(\mathbf{k}') \exp(i\mathbf{k}' \mathbf{A}_l) \quad (10.5)$$

are the Fourier coefficients of the energy $E_n(\mathbf{k}')$ of the n th band. The range of $\mathbf{k}'$ summation, numbering of energy bands, and the coefficients $\varepsilon_n(\mathbf{A}_l)$ in (10.5) correspond to the supercell chosen; N is the number of supercells in the macrocrystal. Let $E_n^{\min}, E_n^{\max}$ be the minimum and maximum values of the energy in the n th band. Introducing $\Delta E_n = \frac{1}{2} (E_n^{\max} - E_n^{\min})$ and $E_n = E_n^{\min} + \Delta E_n$, we get

$$\begin{aligned} \frac{1}{N} \left| \sum_{\mathbf{k}'} (E_n(\mathbf{k}') - E_n) \exp(i\mathbf{k}' \mathbf{A}_l) \right| &\leq \frac{1}{N} \cdot N \cdot \max \{ |E_n(\mathbf{k}') - E_n| |\exp(i\mathbf{k}' \mathbf{A}_l)| \} \\ &\leq \max \{ |E_n(\mathbf{k}') - E_n^{\min} - \Delta E_n| \} \leq \Delta E_n \end{aligned}$$

The inequality obtained

$$\frac{1}{N} \left| \sum_{\mathbf{k}'} (E_n(\mathbf{k}') - E_n) \exp(i\mathbf{k}' \mathbf{A}_l) \right| \leq \Delta E_n \quad (10.6)$$

is fulfilled for any choice of the supercell, defining the translation vectors $\mathbf{A}_l$, the range of $\mathbf{k}'$ summation, and the band numbering. For any choice of the supercell, $\sum_{\mathbf{k}'} \exp(i\mathbf{k}' \mathbf{A}_l) = N \cdot \delta_{\mathbf{A}_l \mathbf{0}}$. Using (10.6) we have the relation

$$|\varepsilon(\mathbf{A}_l) - E_n \delta_{\mathbf{A}_l \mathbf{0}}| \leq \Delta E_n \quad (10.7)$$

that can be rewritten as

$$|\varepsilon(\mathbf{0}) - E_n| \leq \Delta E_n, \quad |\varepsilon(\mathbf{A}_l)| \leq \Delta E_n \quad (10.8)$$

Hence,

$$\begin{aligned} \varepsilon(\mathbf{A}_l) &\rightarrow 0, \quad \varepsilon(\mathbf{0}) \rightarrow E_n \\ \Delta E_n &\rightarrow 0 \end{aligned} \quad (10.9)$$

On increasing the size of the supercell, one can approach the limits in (10.9) as closely as desired. When the size of the supercell increases, the number of energy bands in some fixed energy interval ΔE increases proportionally, and the width ΔE_n of the n th band decreases. From (10.8), it follows that the narrower the energy bands of the perfect crystal (in the usual band numbering for the primitive cell), the smaller will be the unit cell for which one can neglect on the right side of (10.4) all the terms with $A_l \neq A_i$ and consider the approximate equation

$$\hat{H}\tilde{W}(\mathbf{r} - \mathbf{A}_i) = \varepsilon_n(0)\tilde{W}(\mathbf{r} - \mathbf{A}_i) \quad (10.10)$$

This equation is written for the Wannier function of the i th supercell. Due to (10.9), $\varepsilon_n(0)$ can be considered as the average energy of the n th band (in the supercell classification of crystalline states). In fact, (10.10) corresponds to the molecular cluster having the shape of the supercell. The Bloch functions of the macrocrystal can be constructed from the cluster one-electron states:

$$\Psi_n(\mathbf{k}, \mathbf{r}) = \frac{1}{N} \sum_{\mathbf{R}_l} \exp(i\mathbf{k} \cdot \mathbf{R}_l) \tilde{W}(\mathbf{r} - \mathbf{A}_l) \quad (10.11)$$

This consideration is the foundation of the approach originally called “the cyclically embedded-cluster” model [681]: the crystal is divided into the sets of regions chosen in the shape of a Wigner–Seitz supercell of the perfect crystal. The central region A contains the defect with its surrounding; the other regions together form the rest of the crystal. We refer the reader to [681] for the mathematical details of this approach. We note only that in the limit when the region A is the whole crystal, this model gives the traditional HF–LCAO equations for a defective crystal considered as a large molecule. In the other limit, when the defect potential is equal to zero, the cyclic cluster of the perfect crystal is obtained. The cyclically embedded-cluster model is relatively simple in implementation and has been used for point defects in ionic [682] and covalent [681] crystals. The drawback of the model is that it does not take into account the polarization of the crystal by the perturbative potential of the defect.

The consideration above using a Wannier function for the supercell shows that the molecular-cluster model is more appropriate for the solids with the relatively narrow (1–3 eV) upper valence bands and sufficiently large energy gap. For ionic insulating crystals, these conditions are fulfilled, and the convergence of the results with increasing cluster size is rapid. The results of recent molecular-cluster calculations [418] confirmed these conclusions made about thirty years before [683]. As an example, we mention the localized orbitals approach used to introduce the embedded-cluster model of α -quartz [684]. The localized orbitals are constructed by applying various localization methods to canonical HF orbitals calculated for a succession of finite molecular clusters of increased size with appropriate boundary conditions. The calculated orbitals span the same occupied Fock space as the canonical HF solutions but have the advantage of reflecting the true chemical nature of the bonding in the system.

In strongly ionic systems, where coupling between the cluster and the background is mainly by classical Coulomb interactions, the long-range forces from the background can be accounted for by a Madelung term. A higher level of approximation applies a shell model for the environment, *that is*, places a set of ions with rigid positive cores and polarizable, negatively charged shells around the cluster. The parameters of this shell model can be determined, *for example*, from self-consistent calculations on model systems. The charges in the embedding point charge model or in the shell model must be determined self-consistently with charges in the cluster [284]. Except for ionic solids, the interaction between the cluster and the background is quantum mechanical in nature, *that is*, the electronic equation is to be solved.

A rigorous mathematical basis for the separation of cluster and background is provided by Green-function (GF) techniques. There are essentially two possible ways: the perturbed-crystal and the perturbed-cluster approaches. In the former approach, it is assumed that the defect introduces a perturbation relative to the perfect crystal, localized to the cluster. If the GF of the perfect crystal is known in any localized basis representation, and the matrix elements of the perturbation can be constructed, the GF of the perturbed crystal can be calculated [284]. The perturbed-crystal approach looks conceptually like the cleanest and most sophisticated solution as far as the description of the crystalline background is concerned. The problems arise more with the cluster. The perturbation should be constructed self-consistently and at the same level as the crystal potential. The perfect-crystal problem can easily be solved on a plane-wave basis, but then the solutions must be transformed into Wannier functions in order to construct the perturbation. Alternatively, a localized basis set can be used for the perfect crystal in the first place. The perturbed-crystal model is most often used in metals where the screening effect of electrons is strong, and the extent of atomic displacements is smaller.

The perturbed-cluster approach [685,686] is formulated in the LCAO approximation and is based on the following sequence of steps [687]: (a) subdivide the entire defect system into a molecular cluster (C), containing the defect, and an external region (D), the indented crystal; (b) calculate the wavefunction for the molecular cluster in the field of the indented crystal; (c) correct the cluster solution in order to allow for the propagation of the wavefunction into the indented crystal while generating the density matrix of the defect system. Steps “b” and “c” are repeated to self-consistency. The corrective terms in step “c” are evaluated by assuming that the density of states projected onto the indented crystal is the same as in the perfect host crystal (fundamental approximation).

With respect to standard molecular-cluster techniques, this approach has some attractive features: explicit reference is made to the HF-LCAO periodic solution for the unperturbed (or perfect) host crystal. In particular, the self-embedding-consistent condition is satisfied, that is, in the absence of defects, the electronic structure in the cluster region coincides with that of the perfect host crystal; there is no need to saturate dangling bonds; the geometric constraints and the Madelung field of the environment are automatically included. With respect to

the supercell technique, this approach does not present the problem of interaction between defects in different supercells, allows a more flexible definition of the cluster subspace, and permits the study of charged defects. The perturbed-cluster approach is implemented in the computer code EMBED01 [687] and applied in the calculations of the point defects both in the bulk crystal [688] and on the surface [689]. The difficulties of this approach are connected with the lattice-relaxation calculations.

Concluding this section we compare the results obtained in the supercell and perturbed-cluster HF-LCAO treatment for the cation vacancy in MgO [690]. The supercells with 16, 32, and 64 atoms have been considered. The perturbed cluster was chosen so that the most important effects of electronic rearrangement and ionic relaxation occur within the cluster, *that is*, the cluster included sufficiently large number of oxygen ions, which are the most polarizable species (perturbed clusters of 7, 13, and 25 atoms were considered). For the largest supercell (64 atoms) and the largest perturbed cluster (25 atoms), the cation-vacancy-formation energy was obtained (in eV) as 1.58 (1.48) and 1.29 (1.19), respectively. In brackets are given the formation energies after relaxation of first-neighbor oxygen; this relaxation is close in both models—0.36 a.u and 0.37 a.u for the supercell and perturbed cluster, respectively. This agreement can be called close.

The majority of the point-defect calculations are now made with the use of the supercell model as it allows use of the computer codes developed for the perfect-crystal calculations. The examples of supercell LCAO calculations of some point defects in the metal oxides are given in the next sections.

10.2 Point Defects in Binary Oxides

10.2.1 Oxygen Interstitials in Magnesium Oxide: *Supercell LCAO Calculations*

Calculations on interstitial oxygen atoms O_i in MgO crystal are of interest because of the possibility of their formation as a primary product during radiation damage.

Irradiation of alkali halides (MX) leads to the formation of primary pairs of Frenkel defects, namely, F centers (electrons trapped at anion vacancies) and interstitial atoms X^0 . The latter are chemically active and immediately form diatomic molecular-type defects X_2^- (H centers), each of which is centered on one anion lattice site.

However, much less is known about interstitial defects in MgO crystals. The efficient creation of F centers under irradiation is known and means that complementary interstitial O_i atoms should also be formed. However, the volume change due to irradiation of MgO is surprisingly small, in contrast to that accompanying the formation of H centers in alkali halides. A diffusion-controlled process related to O_i defects was experimentally observed and characterized by an activation energy of 1.6 eV. This was ascribed to the destruction of some complexes. Therefore,

the theoretical study of the stability and configuration of oxygen-atom interstitials in MgO is of importance in trying to understand radiation damage of this important ceramic material.

We discuss here the results of all-electron HF and semiempirical valence-electron CNDO–LCAO calculations of oxygen interstitials in MgO crystal [666]. The supercells of 8, 16, and 32 atoms (S8, S16, S32, see Sect. 10.1.2) were taken in HF calculations; in CNDO calculations, the larger supercells were taken to study the convergence of the results obtained. The different configurations for the interstitial oxygen atom were considered, corresponding to an oxygen atom at the volume (v), face (f), and edge (e) centers, respectively, see Fig. 10.2. The dumbbell-shaped configurations vd , fd , and ed are formed when the interstitial oxygen atom O_i is moved toward the nearest-neighbor O^{2-} lattice anion along $\langle 111 \rangle$, $\langle 110 \rangle$, and $\langle 001 \rangle$ directions, respectively. The lattice oxygen anion is simultaneously displaced from its site along the same direction; the center of the dumbbell formed is at the lattice site. To settle the question of an adequate size for the supercell, the calculations for v , f , and e configurations are made for supercells containing 9, 17, and 33 atoms. The defect energy levels in the bandgap are observed to change between the 9-atom and 33-atom supercells, although the influence of supercell size on the charge distribution is relatively small. In HF–LCAO calculations, the size of the supercell is limited by the computational facilities available. Therefore, the convergence of the properties of these defects was investigated also by means of the semiempirical complete neglect of differential overlap (CNDO) approximation, using a code, written by Tupitsyn (<http://wgc.chem.pu.ru/~valera/cndo/manual.html>) for the CNDO band calculations. In the CNDO approximations, it was possible to use supercells containing 65, 129, and 257 atoms, obtained by enlarging all three smaller supercell translation vectors by a factor of two. It was found that both the charge distribution and the defect levels in the bandgap for the larger supercells were close to those obtained for the 33-atom supercell.

HF and CNDO calculations were done to investigate convergence with respect to supercell size. All basis atoms, except those involved in a defect, occupy lattice sites. The CNDO results show that the defect-formation energy changes by only 0.3% on increasing the supercell size from 33 to 257 atoms. The HF energies generally change by less than 0.03% on increasing the supercell from 17 to 33 atoms. This suggests that the variations observed in the CNDO energies may be due more to inherent approximations in the method than to defect interactions and that a 33-atom supercell is definitely sufficient. If we were only interested in the energy of the unrelaxed crystal, then an S8 supercell, containing eight primitive unit cells, would in fact be adequate. However, the number of shells of atoms around the defect that may be relaxed is dependent upon the size of the supercell, and the 33-atom supercell is the smallest that can be used to obtain quantitatively accurate results.

In Table 10.3 is given the optimized distance between the two dumbbell atoms calculated by both the HF and CNDO methods. The labels S16, S64, and S128 are used for supercells containing 16, 64, and 128 primitive unit cells, respectively. q is the charge on each of the two oxygen atoms in the dumbbell configuration, and d is the optimized distance between the two O atoms in the dumbbell. ΔE_d is the energy change on forming the dumbbell from an interstitial in the rigid lattice.

Table 10.3 Results of HF and CNDO calculations for O atom interstitials in MgO (only the dumbbell oxygen atoms are relaxed)[666]

Configuration	Supercell	$d(\text{\AA})$	$q(e)$	$-\Delta E_d$
<i>ed</i>	S16 (HF)	1.310	-1.160	—
	S16 (CNDO)	1.280	-0.944	32.6
	S64 (CNDO)	1.280	-0.944	32.6
	S128 (CNDO)	1.282	-0.944	32.6
<i>vd</i>	S16 (HF)	1.355	-1.070	—
	S16 (CNDO)	1.394	-0.918	7.9
	S64 (CNDO)	1.392	-0.917	7.9
	S128 (CNDO)	1.393	-0.917	7.8
<i>fd</i>	S16 (HF)	1.372	-1.033	—
	S16 (CNDO)	1.369	-0.929	3.2
	S64 (CNDO)	1.366	-0.928	3.2
	S128 (CNDO)	1.369	-0.928	3.3

The charge q on each of the two ions in the dumbbell is close to -1 ; negative charge on the dumbbell in excess of -2 is being made up by a slight deficit on the next-nearest ions. The optimized HF values for d are close to those found for a 17-atom supercell using the full-potential linear muffin-tin orbital (FPLMTO) method [691]. The optimized d values in the CNDO approximation are also close to those obtained using the HF and LMTO methods. Since the CNDO method is semiempirical, these calculations were performed with all atoms except the added interstitial, or the two dumbbell atoms, fixed on their normal lattice sites. In the HF calculation, d was first optimized for a crystal with all except the defect atoms on perfect lattice sites. The charges on the two dumbbell atoms are again close to -1 , and the values of d and q (the charge on each of the dumbbell atoms) in Table 10.3 are from these calculations. The optimum relaxed positions of the near-neighbor ions were then determined iteratively, and finally the value of ΔE_d was reoptimized.

The values of d and q with the relaxed positions are in Table 10.4 together with the energy changes that accompany the formation of a dumbbell from the corresponding interstitial (*ed* from *e*, and so forth), and the further energy changes associated with relaxation of near neighbors. ΔE_d is the difference between the total energy of the unrelaxed crystal in the dumbbell configuration and that for the unrelaxed crystal with the added O atom in the interstitial site, ΔE_{rel} is the further energy change (in eV) accompanying the relaxation of near neighbors.

Subscripts 1,2 mean nearest- and next-nearest atoms (of that species) to the dumbbell, see Fig. 10.2c. For *ed*, $\delta O_{\parallel}$ is the displacement parallel to the axis of the dumbbell and $\delta O_{\perp}$ the displacement perpendicular to the axis of the dumbbell. In each case, all the atoms of a symmetry-related set that lies wholly within the supercell were allowed to relax.

The importance of supercell size is shown, for example, by the calculations for *vd* where for S8, only the six nearest-neighbor Mg atoms may be relaxed because the nearest O atoms lie on the supercell boundary. This may be why comparable

Table 10.4 Results of HF calculations of interstitial oxygen in MgO using S16 supercell [666]

Type of dumbbell	d (Å)	$q(e)$	$-\Delta E_d$ (eV)	$-\Delta E_{\text{rel}}$ (eV)	Relaxations δ (Å)
<i>ed</i>	1.319	21.001	28.88	0.12	$\delta_{\text{Mg}_1} = 0.241$
					$\delta_{\text{Mg}_2} = 0.051$
					$\delta_{\text{Mg}_2} = 0.051$
					$\delta_{\text{O}} = 0.0245$
					$\delta_{\text{O}} = 0.1030$
<i>vd</i>	1.383	21.049	15.94	0.27	$\delta_{\text{Mg}} = 0.077$
<i>fd</i>	1.324	21.010	7.15	2.59	$\delta_{\text{O}} = 0.1057$
					$\delta_{\text{Mg}_1} = 0.152$
					$\delta_{\text{Mg}_2} = -0.010$
					$\delta_{\text{O}} = 0.0997$

FPLMTO calculations [691] for S8 found the *vd* defect to be slightly more stable than *fd*, whereas in HF calculations the reverse is true (Table 10.4). The decrease in energy ΔE_d on forming a dumbbell in a perfect lattice from a *v*-, *f*-, or *e*-centered interstitial O atom (calculated as the difference between the HF total energies for the two configurations) is largest (28.9 eV) for the *ed* center and smallest for the *fd* center (7.1 eV). The former result is to be expected because of the greater overlap in the *e* configuration. The CNDO results for ΔE_d agree with the HF results only qualitatively, but they serve to confirm convergence with increasing size of supercell, which was the reason for doing the calculations. The further energy gain on the relaxation of near neighbors, $-\Delta E_{\text{rel}}$, was found to be small compared to that on forming the dumbbells, which evidently provides a very effective mechanism for reducing charge overlap.

The optimized displacements are given in Table 10.4, and these are seen not to exceed 0.1–0.2 Å. With respect to the most stable *fd* relaxed dumbbell configuration, the *vd* and *ed* configurations are less favorable by 1.31 and 1.86 eV, respectively. So O atoms formed in MgO during radiation damage will become trapped in face-centered dumbbell configurations. The excitation of this configuration to the relaxed face-centered interstitial requires an energy of 2.12 eV, which would therefore be the activation energy for diffusion of *fd*. This energy may be compared with 1.45 eV the activation energy for oxygen-atom diffusion calculated by the supercell FPLMTO approach [691] and the 1.6 eV for some diffusion-controlled process involving interstitial oxygen atom that has been observed experimentally in MgO.

10.2.2 Neutral and Charged Oxygen Vacancy in Al₂O₃ Crystal: Supercell and Cyclic-Cluster Calculations

Aluminum oxide (α -Al₂O₃, corundum) has a large number of technological applications. Due to its hardness, its chemical and mechanical stability at high temperatures, and its electronic properties as a widegap insulator; it is used for the

fabrication of abrasives, as a carrier for thin metal films in heterogeneous catalysis, and in optical and electronic devices.

The structural and electronic properties of α -Al₂O₃ are altered by defects such as oxygen vacancies, which can be formed as a result of the bombardment of the oxide with high-energy particles. Neutral oxygen vacancies (F centers) and positively charged oxygen vacancies (F⁺ centers) in aluminum oxide have been investigated in a number of experimental and theoretical studies. Experimental and theoretical results agree that the two electrons of the F center are localized and remain in the vacancy vicinity, indicating a singlet ground state. Despite numerous investigations, the defect-formation energies of the F center, $E_f(\text{F})$, and the F⁺ center, $E_f(\text{F}^+)$, are rarely given in the literature. To our knowledge, no experimental data are available up to now.

In [692] supercell calculations based on the orthogonalized linear combination of atomic orbitals (OLCAO) method within the local density approximation (LDA) were performed. In this case, the oxygen vacancy was modeled by removing one oxygen atom from the cell. They obtained a defect-formation energy of $E_f(\text{F}) = 38.36$ eV for the neutral oxygen vacancy without relaxation of the geometry. When the four nearest-neighbor aluminum and 12 next-nearest-neighbor oxygen atoms around the vacancy (see Fig. 2.19) were allowed to relax, the defect-formation energy decreased to $E_f(\text{F}) = 5.83$ eV. This corresponds to a relaxation energy of $E_{\text{rel}} = 32.53$ eV. The distance of the neighboring aluminum atoms to the vacancy increased by about 16%, and the distance of the oxygen neighbors by about 8% with respect to the unrelaxed structure. Similar values were obtained for the F⁺ center. The defect-formation energy for the F center was calculated with respect to an isolated neutral O atom, see (10.1), using the difference of the total energy of the supercell with and without vacancy and adding the energy of the free oxygen atom E_{O} .

In [693], a 65-atom molecular cluster is used that was treated semiempirically at the INDO level and embedded in the electrostatic field generated by multipoles. To model the F and F⁺ centers in corundum, additional 2s and 2p Slater-type atomic orbitals were placed in the vacancy after removing one O atom. The relaxation of the four aluminum atoms nearest to the vacancy resulted in an outward displacement by 2–3% and 5–6% for the F and F⁺ center, respectively. From the 12 next-nearest oxygen atoms, only two were allowed to relax. In contrast to the results of [692], the two oxygen atoms moved toward the vacancy by about –2.2% and –4.6% for the F and F⁺ center, respectively. Defect-formation energies were not calculated.

The neutral oxygen vacancy was investigated in [694] by supercell-DFT calculations within the generalized gradient approximation (GGA) using a plane-wave basis and ultrasoft Vanderbilt pseudopotentials. The calculated defect-formation energy is $E_f(\text{F}) = 7.13$ eV and $E_f(\text{F}) = 7.08$ eV for the F center without and with the relaxation of the nearest aluminum and next-nearest oxygen atoms, at the oxygen-rich limit. As a reference for the calculation of the defect-formation energy, $E_{\text{O}} = 0.5E_{\text{O}_2}$ was taken instead of a free oxygen-atom energy E_{O} . The aluminum atoms show an inward relaxation of –1.5%; the positions of the oxygen atoms are almost unchanged (–0.1%).

The intrinsic defects in $\alpha\text{-Al}_2\text{O}_3$ were also studied in [695] by the supercell DFT–PW method (the supercell contained up to 120 atoms). The relaxation of the four nearest aluminum atoms, 12 next–nearest oxygen atoms, and two next–next–nearest aluminum atoms around the neutral and positively charged oxygen vacancy was taken into account. The results given in [695] show an average inward relaxation of the nearest Al for the neutral oxygen vacancy of about -1.5% and a slight inward relaxation of the next–nearest O atoms by -0.4% . For the single positively charged oxygen vacancy, they find an outward relaxation of the nearest Al atoms of 4.6% . The oxygen atoms relax by -1.4% toward the vacancy. The defect-formation energy of the neutral oxygen vacancy $E_f(\text{F}) = 13 \text{ eV}$ was calculated at the oxygen-rich limit.

It is seen that the results of the different theoretical simulations of oxygen vacancies in corundum are contradictory. An attempt to resolve this contradiction was made in [696] where the energies of the formation of an F center and an F^+ center were calculated and relaxation effects were investigated with a combination of HF, DFT, and semiempirical methods in the framework of supercell and cyclic-cluster models. All supercell LCAO calculations were made using the CRYSTAL code [21], the details of the basis and computational parameters choice can be found in [696]. The semiempirical cyclic-cluster calculations were made using the MSINDO code developed in the Hannover theoretical chemistry research group [246], see Chap. 6. The cyclic cluster was embedded in an infinite field of point charges using the Ewald summation technique [697]. The charges for the embedding can either be calculated self-consistently from the atoms of the cyclic cluster using a Lowdin population analysis at each SCF cycle or can be kept fixed at the values of the perfect crystal.

The scheme of the SCM realization, discussed in Sect. 10.1.3, requires in stage 1 the calculations of the perfect crystal. The perfect corundum crystal has a rhombohedral structure with the space group $R\bar{3}c(D_{3d}^6)$, see Chap. 2). The oxygen atoms form a hexagonal close-packed structure; the aluminum atoms occupy $2/3$ of the octahedral vacancies so that all Al atoms have the same environment. Every O atom has two neighboring Al atoms at a distance of $r_1 = 1.86 \text{ \AA}$ and two others at a distance of $r_2 = 1.97 \text{ \AA}$. The primitive rhombohedral unit cell consists of two Al_2O_3 formula units with experimental lattice parameters $a = 5.128 \text{ \AA}$ and $\alpha = 55.333^\circ$.

Using the transformation of basic rhombohedral lattice translation vectors with the matrix

$$l = \begin{pmatrix} 2n_1 & n_1 & 0 \\ -n_1 & n_1 & 0 \\ 0 & 2n_1 & n_2 \end{pmatrix}, \quad L = 3n_1^2 n_2 \quad (10.12)$$

one obtains the hexagonal setting of the corundum structure. Its unit cell ($n_1 = n_2 = 1$) consists of $L = 3$ primitive unit cells. The lattice parameters in this hexagonal setting are $a = 4.763 \text{ \AA}$ and $c = 13.003 \text{ \AA}$. Furthermore, corundum has two internal structure parameters $u_{\text{Al}} = 0.352$ and $u_{\text{O}} = 0.306$, which define the Al and O positions, respectively (see Sect. 2.3.5). The experimental heat of atomization is $\Delta_a H_0 = 31.60 \text{ eV/Al}_2\text{O}_3$. This has been obtained by the experimental heat of

Table 10.5 HF and DFT cohesive energies E^{HF} and E^{DFT} (eV/Al₂O₃) obtained from band calculations using different sets ($s_1s_2s_3$) of $\mathbf{k}$ -points [696]*

Unit cell	($s_1s_2s_3$)	L	$N_{\text{efficient}}$	E^{HF}	E^{DFT}
Rhombohedral	(222)	8	Al ₁₆ O ₂₄	21.47	29.70
	(333)	27	Al ₁₀₈ O ₁₆₂	21.50	29.72
Hexagonal	(111)	3	Al ₁₂ O ₁₈	—	29.84
	(221)	12	Al ₄₈ O ₇₂	21.49	29.70
	(331)	27	Al ₁₀₈ O ₁₆₂	21.50	29.71
	(662)	216	Al ₄₃₂ O ₁₂₉₆	21.50	29.72

* $E_{\text{exp}} = 31.60$ eV

formation of the solid ($\Delta_f H_0(\text{Al}_2\text{O}_3) = -17.22$ eV) and the heats of formation of the corresponding atoms in the gas phase ($\Delta_f H_0(\text{Al}) = 3.35$ eV, $\Delta_f H_0(\text{O}) = 2.56$ eV).

As was noted in Sect. 10.1.3, the first stage of supercell–cyclic-cluster calculations of the defective crystal consists of the band-structure calculations of the perfect crystal to choose the supercell for its modeling. Table 10.5 shows the results for the HF and DFT–LCAO band calculations of the perfect Al₂O₃.

The geometrical parameters were fixed to the experimental values. The cohesive energy per formula unit was calculated as the difference between the total energy per Al₂O₃ unit in the crystal and the sum of the energies of the corresponding free atoms. The calculations were made using Monkhorst–Pack sets (s_1, s_2, s_3) of $\mathbf{k}$ points, which correspond to supercells of L -primitive unit cells consisting of $N_{\text{efficient}}$ atoms. E_{coh} calculated corresponds to the experimental heat of atomization $\Delta_a H_0$ except for the zero-point energy that is neglected in the calculation of E_{coh} . The energies of the free Al and O atoms were obtained by increasing the basis sets successively with diffuse sp-functions until the energies of the free atoms were converged, see Chap. 8. The HF cohesive energy of 21.50 eV/Al₂O₃ is too low by 10.10 eV/Al₂O₃ compared with the experimental value of 31.60 eV/Al₂O₃. This discrepancy is mainly due to the missing correlation and the incompleteness of the basis set [698].

The DFT results, using the PWGGA–PWGGA exchange–correlation functional (29.72 eV/Al₂O₃), are closer to the experiment. But the cohesive energy is still underestimated by about 1.88 eV/Al₂O₃. The bandgap $E_g = 6.28$ eV from DFT calculation is about 0.4 eV larger than the value obtained in [695] but still too small compared with the experimental range of the bandgap between 8.5 and 9.9 eV. The bandgap of 17.51 eV calculated at the HF level is much too high in line with experience.

The results of the cyclic-cluster MSINDO calculations are shown in Table 10.6.

Since the CCM does not involve a summation over the reciprocal space, the size of the cyclic cluster was increased in direct space to obtain convergence for the cohesive energy. Each cluster was embedded in an infinite Madelung field of point charges. Again, the geometry was fixed to the experimental values to enable the comparison with the results of the supercell calculations. The MSINDO-optimized lattice parameters ($a = 4.779$ Å, $c = 13.074$ Å), internal structure parameters

Table 10.6 Cohesive energies E^{MSINDO} (eV/Al₂O₃) for cyclic-cluster MSINDO calculations using different cyclic clusters [696]

Cluster	L	n_1	n_2	E^{MSINDO}
Al ₁₂ O ₁₈	3	1	1	35.45
Al ₄₈ O ₇₂	12	2	1	31.17
Al ₉₆ O ₁₄₄	24	2	2	31.17
Al ₁₀₈ O ₁₆₂	27	3	1	31.09
Al ₁₉₂ O ₂₈₈	48	4	1	31.09

Table 10.7 HF and DFT defect-formation energies $E^{\text{HF}}(\text{F})$ and $E^{\text{DFT}}(\text{F})$ (eV) for the neutral oxygen vacancy in Al₂O₃ obtained from supercell calculations using different sets (s_1, s_2, s_3) of $\mathbf{k}$ -points [696]

(s_1, s_2, s_3)	$E^{\text{HF}}(\text{F})$	$E^{\text{DFT}}(\text{F})$
(1 1 1)	16.55	13.08
(2 2 2)	16.38	12.92
(3 3 3)	16.38	12.24
		PW-DFT GGA [695]

($u_{\text{Al}} = 0.354, u_{\text{O}} = 0.301$), and the cohesive energy ($E_{\text{coh}} = 31.16$ eV/Al₂O₃) [697] of the perfect α -Al₂O₃ are in very good agreement with the experimental data. A bandgap of $E_g = 10.9$ eV was obtained by a 25×21 configuration interaction (CI) calculation for the defect-free Al₁₉₂O₂₈₈ cluster. This value is at least 1 eV above the experimentally observed range of the bandgap of the perfect crystal, but there are no forbidden transitions, which is an indication of a direct bandgap, in agreement with the generally accepted opinion. The valence-band maximum (VBM) consists of O 2*p*-orbitals, while the conduction band minimum (CBM) consists mainly of Al 3*s* orbitals in agreement with other theoretical [695] and experimental results. The cohesive energies for the experimental geometry of α -Al₂O₃ given in Table 10.6 show a fast convergence with increasing cluster size. Already the energy value of the Al₄₈O₇₂ cluster that corresponds to $L = 12$ primitive unit cells is, with 31.17 eV/Al₂O₃, close to the calculated limit of 31.09 eV/Al₂O₃. Therefore, the experimental value of 31.60 eV/Al₂O₃ is reproduced with a deviation of about 0.50 eV/Al₂O₃.

In stage 2 (the supercell calculation of a defective crystal, see Sect. 10.1.3), for the simulation of the F center in α -Al₂O₃, a supercell was created by using the transformation matrix (10.12) with $n_1 = 2$ and $n_2 = 1$ ($L=12$). One oxygen atom was removed from the supercell, and the defect-formation energy for the F center was calculated for different $\mathbf{k}$ -point grids ($s_1 s_2 s_3$), keeping the geometry fixed to the experimental values. For the calculation of the defect-formation energy, $E_{\text{O}} = 0.5E_{\text{O}_2}$ was used. Table 10.7 shows the results using the HF and the DFT (PWGGA–PWGGA) approach.

The defect-formation energy shows fast convergence with the increase of the number of sampling $\mathbf{k}$ -points. Already the $(2 \times 2 \times 2)$ grid gives the converged HF

Table 10.8 Cyclic-cluster MSINDO defect-formation energies $E^{\text{MSINDO}}(\text{F})$ and $E^{\text{MSINDO}}(\text{F}^+)$ (eV), distances r_1 and r_2 (Å) of nearest-neighbor (NN) and next-nearest neighbor (NNN) atoms from the defect, and changes of the distances $\Delta r(\%)$ for the unrelaxed and relaxed F and F^+ center in Al_2O_3 using the $\text{Al}_{192}\text{O}_{288}$ cyclic cluster [696]

	Unrelaxed	Relaxed (NN + NNN)
F center	$E^{\text{MSINDO}}(\text{F}) = 12.32$, $r_1 = 1.86$, $r_2 = 1.97$	$E^{\text{MSINDO}}(\text{F}) = 11.81$, $r_1 = 1.872$ ($\Delta r = 0.5$), $r_2 = 2.053$ ($\Delta r = 4.0$)
F^+ center	$E^{\text{MSINDO}}(\text{F}^+) = 12.22$, $r_1 = 1.86$, $r_2 = 1.97$	$E^{\text{MSINDO}}(\text{F}^+) = 10.33$, $r_1 = 1.971$ ($\Delta r = 6.0$), $r_2 = 2.089$ ($\Delta r = 6.0$)

energy of $E_f^{\text{HF}}(\text{F}) = 16.38$ eV. For the DFT calculations, the same set of $\mathbf{k}$ -points was used to yield a defect-formation energy of $E_f^{\text{DFT}}(\text{F}) = 12.92$ eV, which is about 3.46 eV lower than the HF result.

In stage 3 relaxation, effects were included in the simulation of the F and the F^+ centers in $\alpha\text{-Al}_2\text{O}_3$ using the MSINDO cyclic-cluster calculations (Table 10.8).

The $\text{Al}_{192}\text{O}_{288}$ cyclic cluster ($n_1 = 4$, $n_2 = 1$, $L = 48$) was chosen for the simulations. One oxygen atom was removed from the cyclic cluster to create the F center, keeping the system neutral. To model the F^+ center the charge of the system was set to +1 after removing one oxygen atom. In both cases, the cyclic cluster was embedded in the Madelung field of the perfect crystal. The charges for this embedding were the Löwdin charges calculated from the simulation of the corresponding perfect cyclic cluster. In contrast to the standard supercell model of a periodic point defect, no artificial neutralizing background and additional charge corrections are needed in the cyclic-cluster model as the point defect is not periodically repeated. The four nearest-neighbor (NN) aluminum atoms and the 16 next-nearest-neighbor (NNN) oxygen atoms close to the vacancy were allowed to relax using a quasi-Newton method until the residual forces had converged to less than 0.02 eV/Å. The rest of the cyclic cluster was fixed in the experimental geometry. The defect-formation energy of the F^+ center was calculated using as the reference a single oxygen atom energy $E_{\text{O}'} = 0.5E_{\text{O}_2}$ as in the case of the neutral oxygen vacancy. Additionally, one electron is removed from the cluster to create a positive charge, and the chemical potential of the electron μ_e is assumed to be zero, different from the models of the charged defects where the electron is assumed to remain in the lattice. The CCM value for the defect-formation energy of the unrelaxed F center $E_f^{\text{MSINDO}}(\text{F}) = 12.32$ eV is close to the DFT supercell value of $E_f^{\text{DFT}}(\text{F}) = 12.92$ eV and the 13 eV obtained in [695], despite substantial differences in the defect-level positions above the VBM. The latter are 8.1 eV for MSINDO, 4.9 eV for DFT supercell calculation, and 2.3 eV as obtained in [695]. The SCM calculation using the HF method gives a larger defect-formation energy

($E_f^{\text{HF}}(F) = 16.38$ eV). The defect-formation energy of 7.13 eV calculated in [694] is considerably lower than the values obtained in [696]. The defect-formation energy of $E_f(F) = 38.36$ eV calculated in [692] was obtained using the total energy of the oxygen atom. If one uses the same reference [692] and not $1/2E_{\text{O}_2}$, one finds a defect-formation energy of 15.06 eV for the MSINDO cyclic-cluster simulation of the unrelaxed vacancy.

An absorption band of about 6 eV has been assigned experimentally to the F center, indicating a location of a doubly occupied defect level roughly 3 eV above the VBM. The corresponding excitation energies are 1.8 eV and 8.8 eV for DFT and HF calculations [696], respectively. The defect level obtained using the MSINDO–CCM method consists mainly of Al 3s orbitals of the aluminum atoms next to the vacancy. Using a 40×30 CI, the first allowed excitation was found to occur at 3.1 eV for the relaxed structure. Therefore, the excitation energy is underestimated by about 3.0 eV. In comparison, the excitation energy in [695] is 3.52 eV which is also too small.

Concerning the relaxation, the CCM simulations of the F center show that the NN Al atoms increase their distance from the vacancy by 1–4% which agrees well with the corresponding data of 2–6% of [693]. The value from [692] is larger (16%), but the NN Al atoms also show a movement away from the vacancy. This is reasonable since the NN Al atoms are positively charged and should therefore repel each other. Under these circumstances, the inward relaxation to the vacancy (1.5%) of the aluminum neighbors found in [694, 695] is difficult to understand. Their choice of pseudopotentials and of basis set, restriction only by Γ point in BZ might be the reason for the discrepancy. Table 10.7 shows that a Monkhorst–Pack net of at least (222) must be used for the defective supercell to reach convergence with respect to the energy. Using only the Γ point might also influence the relaxation.

Considering the NNN O atoms, an average relaxation of -0.4% toward the vacancy and the total relaxation energy $E_{\text{rel}} = 0.51$ eV were found in the LCAO calculations [696] of the F center. This agrees well with the values -0.1% and -0.4% of [694, 695] indicating that the positions of the oxygen atoms are almost unchanged. An inward relaxation was also found in [693]. In contrast to these results, a large outward relaxation of 8% and $E_{\text{rel}} = 32.53$ eV were found in [692]. The value of 32.53 eV for the relaxation energy appears to be much too high, because this value is larger than the experimental heat of formation for the α -Al₂O₃ (31.60 eV).

A singly occupied defect level occurs in the bandgap in the case of the F^+ center. The results of the CCM calculations for the F^+ center (Table 10.8) indicate a larger relaxation of the NN Al atoms (6.0%) and of the NNN oxygen atoms (-1.2%) compared to the values obtained for the neutral oxygen vacancy. This is reasonable, since the aluminum atoms repel each other more strongly due to the missing electron in the vacancy. In consequence, the relaxation energy ($E_{\text{rel}} = 1.90$ eV) is also larger than the corresponding value for the F center. This trend is confirmed by results found in DFT PW calculations [695]: an outward relaxation of 4.6% for the Al neighbors and an inward relaxation of -1.4% of the oxygen atoms close to

the vacancy, which agree well with the MSINDO–CCM results. The movements found in semiempirical LCAO calculations [693] are slightly larger (5–6% for the Al atoms, –4.6% for the oxygen atoms), but they also confirm the tendency.

The defect-formation energy of the F^+ center is smaller than that of the F center in both the relaxed and the unrelaxed structures using $\mu_e = 0$ for the chemical potential of the electrons. This agrees qualitatively with the results of [695] when compared to their values at $\mathbf{k} = \mathbf{0}$. It was noted that no experimental data for the defect-formation energy are available in the literature for the F and F^+ center in α - Al_2O_3 . The detailed consideration of the results of application of different models and calculation schemes to F and F^+ centers in corundum demonstrate that LCAO methods reproduce well the results of PW calculations for the neutral defect. Furthermore, the LCAO methods are more appropriate for the charged-defect modeling as the artificial defect periodicity is escaped in the LCAO cyclic-cluster approach.

10.2.3 Supercell Modeling of Metal-Doped Rutile TiO_2

Titanium dioxide (TiO_2) is a wide-bandgap material useful in many practical applications (electrochemistry, sun lotions, nanostructured electrodes). The electronic structure of TiO_2 can be strongly influenced by 3d transition-metal dopants that introduce local electronic levels into the bulk energy bandgap and thus shift the absorption edge to the visible region.

The effects of metal doping on the properties of TiO_2 have been a frequent topic of experimental investigation. In particular, according to a systematic study on the photoreactivity and absorption spectra of TiO_2 doped with 21 different metals [699], the energy level and d-electron configuration of the dopants were found to govern the photoelectrochemical process in TiO_2 . The resonance photoemission study [700] was applied to investigate the nature of bandgap states in V-doped TiO_2 in rutile structure.

The computer simulation has been employed to clarify in detail impurity-doping effects. A molecular-cluster approach was extensively adopted, see references in [701]. These cluster calculations have never led to unifying conclusions regarding the effects of doping on the electronic states due to the influence of dangling bonds.

The supercell approach demonstrated its capacity to deal with metal-doped TiO_2 defective crystals in DFT–FPLAPW supercell electronic-structure calculations [701, 702]. It was found that when TiO_2 is doped with V, Cr, Mn, Fe, or Co, an electron-occupied localized level in the bandgap occurs and the electrons are localized around each dopant. As the atomic number of the dopant increases, the localized level shifts to the lower energy. The energy of the localized level due to Co is sufficiently low to lie at the top of the valence band, while the other metals produce midgap states. In contrast, the electrons from the Ni dopant are somewhat delocalized, thus significantly contributing to the formation of the valence band with the O 2p and Ti 3d electrons. These conclusions were made in [701] on the

basis of the DFT FPLAPW calculations on a relatively small supercell consisting of four primitive unit cells stacked along the b - and c -axis of the simple tetragonal lattice. The experimental values of the lattice constants $a = b = 4.594 \text{ \AA}$ and $c = 2.959 \text{ \AA}$ were taken, so that the translation vectors lengths a , b , and c of the orthorhombic supercell equal $4.594 \text{ \AA}$, $9.188 \text{ \AA}$, and $5.918 \text{ \AA}$, respectively. Such a choice of supercell is not optimal as the defect–defect distance R_{d-d} is not the same along the three supercell translation vectors, and the defect–defect interaction corresponds in fact to the smallest distance $R_{d-d} = 4.594 \text{ \AA}$ (the length of the primitive tetragonal unit cell translation in the perfect rutile crystal).

As in the FPLAPW method, the further increasing of the supercell is sufficiently difficult that the dependence of the results on the supercell size was not studied in [701]. Such a study was made in semiempirical cyclic-cluster calculations of Li, Cl, and Br impurities in TiO_2 [703, 704] without preliminary symmetry analysis of the cyclic clusters chosen. Such an analysis was made in [667] and allowed the convergence of the supercell UHF–LCAO calculations of V-doped rutile with the supercell size to be investigated. This first nonempirical supercell LCAO calculation of the defective rutile crystal is discussed here in more detail.

The impurity vanadium atom substitutes for a titanium atom introducing an unpaired electron in the unit cell. The symmetry of the supercell model is described by any of four orthorhombic space groups D_{2h}^1 , D_{2h}^{19} , D_{2h}^{23} , and D_{2h}^{25} . Analyzing the period of the defect for the same supercell size (given L -value) in these groups, it was found that for rutile structure the best choice would be D_{2h}^{25} corresponding to the symmetric transformation of the simple tetragonal lattice translation vectors with matrix (n_1, n_2, n_3) —integers, $n_1 \neq n_2$):

$$l = \begin{pmatrix} -n_1 & -n_2 & n_3 \\ n_1 & n_2 & n_3 \\ n_2 & n_1 & -n_3 \end{pmatrix}, \quad L = 2(n_1^2 - n_2^2)n_3 \quad (10.13)$$

The space group D_{2h}^{25} corresponds to the body-centered orthorhombic lattice of supercells with the translation vectors of equal length in all three translation directions. This means that the point-defect period is also the same in these directions (equidistant configuration of defects). This choice of defective crystal space group ensures the largest defect period for a chosen supercell size (fixed value of L).

The UHF–LCAO calculations of V-doped rutile were made using the CRYSTAL code [21] and Durand–Barthelat pseudopotentials [468]. The atomic basis functions of Ti and O atoms were taken from [313] that were fitted to reproduce the band structure and bonding properties of perfect rutile crystal. The vanadium atom functions were found by fitting these properties of VO_2 crystal in the rutile modification. The accuracy of the calculation was ensured by the choice of the computational parameters of the CRYSTAL code, ensuring a good accuracy of the bielectronic series, the convergence thresholds of the eigenvalues, and total energy and $\mathbf{k}$ -point sampling in BZ.

Table 10.9 The convergence of the results of the unrestricted Hartree–Fock LCAO calculations [667] of the V-doped rutile (defective-crystal space group $D_{2h}^{25} = Immm$; $L = 2(n_1^2 - n_2^2)n_3$)*

(n_1, n_2, n_3)	(1,0,1)	(1,0,2)	(2,1,1)	(3,2,1)	(4,3,1)
L	2	4	6	10	14
Doping (%)	0.25	0.125	0.083	0.050	0.036
N_A	12	24	36	60	84
N_B	120	240	360	600	840
R_{d-d} (Å)	5.45	7.53	10.62	16.69	22.97
E_d (a.u.)	−0.2955	−0.2991	−0.3004	−0.3012	−0.3016
Q_V	2.761	2.760	2.759	2.759	2.759
C_V	1.921	1.924	1.927	1.927	1.927
$N_V^{\alpha-\beta}$	1.115	1.114	1.099	1.099	1.099

* The supercell transformation matrix $l = \begin{pmatrix} -n_1 & -n_2 & n_3 \\ n_1 & n_2 & n_3 \\ n_2 & n_1 & -n_3 \end{pmatrix}$

Table 10.9 shows the results obtained for the supercells of increasing size. The Monkhorst–Pack shrinking factor was taken to be 6 for supercells with $L = 2, 4, 6$, and 4 for supercells with $L = 10, 14$. Table 10.9 gives the integers n_1, n_2 , and n_3 defined according to (10.13) the supercell of the defective crystal consisting of L primitive unit cells and corresponding doping percent, the number of atoms N_A , and atomic basis functions N_B in the supercell, vanadium–vanadium distance R_{d-d} (defect period) in the supercell model. The convergence of the absolute value of the one-electron energy E_d occupied by the unpaired electron is seen. It appears that already the supercell for $L = 6$ is enough to reproduce the vanadium atom charge Q_V , covalence C_V (the sum of the bond orders of the impurity atom with all the crystal atoms), and spin-density $N_V^{\alpha-\beta}$. Using the calculated Q_V and C_V , the total valence $V_{\text{tot}} = 0.5 \left(C_V + \sqrt{4Q_V^2 + C_V^2} \right)$ is 3.88, *that is*, the impurity atom is in oxidation state IV, and the calculated spin density corresponds to the fifth vanadium electron not taking part in the chemical bonding. This result is in accordance with the experimentally found [700] ESR signal for V-doped rutile.

The Fermi energy E_F in the perfect rutile TiO_2 ($E_F = -0.3029$ a.u.) was calculated using the same pseudopotential and basis functions of titanium and oxygen atoms that were used for the defective-crystal calculation. Thus, the V-atom impurity level (occupied by an electron) is relatively close to the perfect-crystal valence-band edge ($\Delta E = -0.3016 + 0.3029 = 0.0013$ a.u. or 0.04 eV). Experimental data [700] predict larger values of ΔE (0.03 a.u. or 0.81 eV). The difference may be explained both by the necessity to take into account the atomic relaxation around the impurity atom and experimental ambiguity in the assignment of the gap states to electrons localized on the V dopant. Bearing in mind the energy gap of 3.0 eV for the perfect crystal and midgap position of the localized level in FPLAPW calculations [701] for V-doped rutile, we conclude that both LCAO (0.04 eV) and FPLAPW (1.5 eV) results for the defect-level position in the bandgap differ from the experimental estimation (0.81 eV).

Table 10.9 shows that the increase of the supercell size moves the defect energy level closer to the valence-band edge. Therefore, DFT-FPLAPW-correlated calculations with the larger supercells would make the agreement with the experimental data better. When using HF-LCAO approach for the calculations, it is important to estimate the possible influence of the electron correlation on the obtained results. We have seen that the highest-occupied level position moves to higher energies when the correlation is taken into account, and this movement may appear different for the perfect and defective crystal, so that the defect-level position in the bandgap also changes. This requires further study.

Nevertheless, the calculation [667] demonstrates (1) the efficiency of the more detailed symmetry analysis for the supercell choice when the periodic defect calculations are made in the complicated crystalline structures with the symmetry of a nonsymmorphic space group and noncubic lattice, (2) the reality of the supercell model for the nonempirical LCAO calculations of the point defects in such a complicated crystalline structure as a rutile structure. and (3) higher efficiency of LCAO basis compared with LAPW basis in the supercell calculations of defective crystals. Moreover, the supercell model allows the dependence of the electronic properties of doped crystals on the doping level to be investigated. In the next section, we consider supercell calculations of defective crystals with perovskite structure.

10.3 Point Defects in Perovskites

10.3.1 Oxygen Vacancy in SrTiO_3

Ternary ABO_3 perovskite materials have numerous technological applications as these materials display a wide range of useful physical and chemical properties. They are important as catalysts, as ceramics, ferroelectrics, superconductors, materials for fuel cells, fusion reactors, and optical and piezoelectric devices.

The properties of perovskite materials are heavily dominated by their oxygen content, as well as by donor- and acceptor-type impurities. An essential contribution to the knowledge of the structural and electronic properties of point defects in these materials comes from theoretical approaches. The results of large-scale computer semiempirical and first-principles modeling of point defects, polarons, and perovskite solid solutions can be found in [705], focusing mostly on KNbO_3 and KTaO_3 .

First-principles calculations of formation energies of point defects were made on BaTiO_3 [706, 707] and NaNbO_3 [708] crystals. Among the various fundamentally and technologically important oxides, SrTiO_3 is a simple structural prototype for many perovskites, in which the detailed investigation of native and dopant defects can lay the theoretical groundwork that can be applied to structurally and chemically more complex perovskite materials [709].

The Green-function method appeared to be very useful for displaying the chemical trends in defect energy levels [710,711]. However, the calculation of other defective-crystal properties (defect-formation energy, lattice relaxation, local-state localization) requires approaches based on molecular cluster or supercell models. Only recently have these models been used in the first-principles calculations to study point defects in SrTiO_3 .

The supercell calculations are made mostly by the DFT PW method [709,712]. The comparative PW (supercell) and LCAO (cluster and supercell) calculations are known for the oxygen vacancy in SrTiO_3 crystal [713–715].

Oxygen vacancies in SrTiO_3 act as effective donors and are important defects in SrTiO_3 . Theoretical simulation of defective SrTiO_3 is very important since modern scanning transmission electron microscopy (STEM) and reflection high-energy electron diffraction (RHEED) combined with atomic-scale electron-energy-loss spectroscopy (EELS) are able to detect the presence of even single impurities and vacancies in SrTiO_3 . A deliberate deviation of oxygen content from the ideal stoichiometry of perovskites is relevant for their numerous high-tech applications as sensors, fuel cells, and microelectronic devices. At low oxygen partial pressure, the electrical conductivity of SrTiO_3 perovskite is controlled by both the concentration and mobility of oxygen vacancies, which act as effective donors; therefore, this material becomes *n*-type conductive. Increasing the partial pressure reduces the carrier concentration, and at high pressures, the conductivity goes through a minimum: the material becomes *p*-type [716,717]. Consequent thermal reduction of oxygen in single-crystalline strontium titanate results in the insulator-to-metal transition, up to a possible superconducting state, accompanied by intensive formation of vacancies and their high density within the skin region [718]. Oxygen vacancies play a noticeable role in the structural transformations in bulk SrTiO_3 , which possesses two relevant structures: the tetragonal antiferrodistortive (AFD) phase and the cubic phase [709]. The latter (Fig. 10.3a) is stable at 105 K, whereas AFD (slightly distorted cubic phase) is stable at lower temperatures.

When simulating a single point defect, the main problem is to understand changes induced by it in the atomic and electronic structure of a host crystal. A perfect SrTiO_3 crystal has a mixed ionic-covalent nature of the chemical bonding, which is not in complete conformity with the formal charges on Sr^{2+} , Ti^{4+} , and O^{2-} ions, see Chap. 9. The formalism of Wannier functions applied for the determination of effective charges and bond populations in several perovskite crystals [719] calculated previously using the density-functional theory (DFT) method [590] gives the atomic charge of +2.55 on titanium and −1.55 on oxygen, whereas the Ti–O bond order is 0.35; only the charge on Sr (+1.95) is close to the nominal ionic value +2, confirming that strontium is ionically bonded in SrTiO_3 . Partly covalent chemical bonding makes the simulations of the structural defects in strontium titanate rather complicated, even in a cubic phase.

The simplest native defect may be described in terms of either a neutral oxygen vacancy (single O atom removed from the lattice site) or neutral F center (the oxygen ion O^{2-} vacancy trapped 2 electrons remaining in a host crystal).

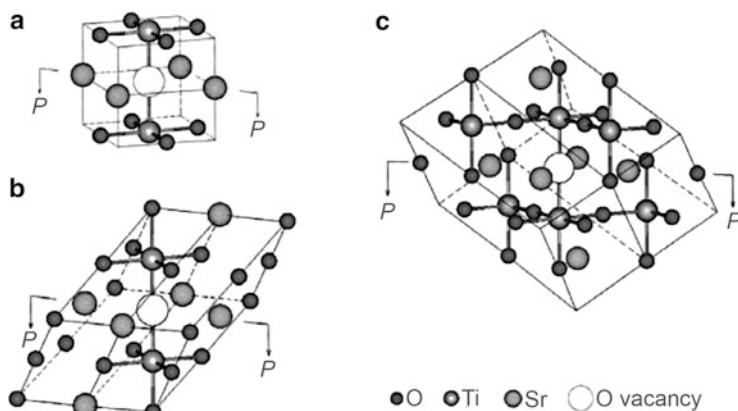


Fig. 10.3 Three types of equidistant crystalline cells with a centered O vacancy for the cubic phase of SrTiO₃ perovskite: (a) simple cubic (sc), (b) face-centered cubic (fcc), and (c) body-centered cubic (bcc). Sticks between the oxygen and titanium ions indicate the partly covalent bonds between them. To construct the difference electron-density plots, each cell is sectioned along the Ti–O–Ti axes by the plane P–P

Theoretical studies mainly predict equal contributions of the $3d$ orbitals of the two nearest titanium ions (Fig. 10.3) into the wavefunction of the F center [712, 713, 717]. According to DFT calculations on a cubic phase of SrTiO₃ perovskite [713], the Mulliken electron charge of 1.1–1.3 is localized in the neutral O vacancy (depending on the supercell size), and 0.6–0.8 are equally divided by the two nearest Ti ions if we consider the F center. This result does not confirm the formal conclusions that the F center is supposed to have released both electrons, whereas the nearest titanium ions change their valence from Ti⁴⁺ to Ti³⁺. The position of the F center level in the optical bandgap of SrTiO₃ is also not completely clear: it is an open question as to whether it lies well below the conduction-band bottom or close to it. The latter is supported by the indirect experimental study on the conductivity of SrTiO₃ ceramics, suggesting that the F center is a rather shallow defect [720].

Supercell *ab initio* calculations on the SrTiO₃ give the values of the formation energy for O vacancy within the range of 6.5–8.5 eV [709, 712, 713, 717], whereas in cluster models [721], removal of an O atom from the lattice has a higher energy cost (>9 eV). However, this value cannot be directly measured experimentally. Conductivity in SrTiO₃ at low partial oxygen pressures depends on the mobility of O vacancies [720]. Experiments performed at high temperatures suggest an energy barrier of 0.86 eV for the F center diffusion in bulk, whereas semiempirical pair-potential calculations on migration on the empty O vacancy result in the barrier of 0.76 eV [722].

In [715] the results of both LCAO (made with the CRYSTAL code [21]) and PW (made with the VASP code [723]) DFT calculations on the F center in a cubic phase of SrTiO₃ perovskite are analyzed, combining the advantages of LCAO and plane-wave formalisms. The lattice structural relaxation around an oxygen vacancy was

optimized for supercells of different shapes and sizes. This is important as DFT PW calculations [709] show the strong dependence of the results on the supercell size (it was concluded that at least a $4 \times 4 \times 4$ supercell of 320 atoms is needed to describe the structural parameters of an oxygen vacancy accurately). In [715], the supercells were obtained by a consequent equidistant extension of crystalline lattice vectors (Fig. 10.3), increasing the supercell size from 80- up to 320-atom cells, in order to eliminate the interaction of periodically repeated point defects and to reach the limit of a single F defect. These supercells are described by transformation matrices

$$\begin{pmatrix} n & 0 & 0 \\ 0 & n & 0 \\ 0 & 0 & n \end{pmatrix}, \quad \begin{pmatrix} 0 & n & n \\ n & 0 & n \\ n & n & 0 \end{pmatrix}, \quad \begin{pmatrix} -n & n & n \\ n & -n & n \\ n & n & -n \end{pmatrix} \quad (10.14)$$

where n is varied between 2 and 4. The corresponding equidistant supercells form *sc*, *fcc*, and *bcc* lattices ((cases a), b), and c) in Fig. 10.3, respectively). The ratio of volumes for the supercells extended from the primitive unit cell using matrices (10.14) with the same n is

$$V_{\text{bcc}} = 2V_{\text{fcc}} = 4V_{\text{sc}} \quad (10.15)$$

Supercells with extensions $3 \times 3 \times 3$ (135 atoms) and $4 \times 4 \times 4$ (320 atoms) form a simple cubic lattice (Fig. 10.3a). In turn, supercells with the *fcc* extensions $2\sqrt{2} \times 2\sqrt{2} \times 2\sqrt{2}$ (80 atoms) and $3\sqrt{2} \times 3\sqrt{2} \times 3\sqrt{2}$ (270 atoms) are rhombohedral with a 60° angle between the lattice vectors, see Fig. 10.3b. Lastly, for a 160-atom rhombohedral *bcc* supercell (extension $2\sqrt{3} \times 2\sqrt{3} \times 2\sqrt{3}$), the angle is 109.47° . For all three types of equidistant cells shown in Fig. 10.3, their shapes correlate with the orientation of the --Ti--O--Ti-- axis; it may be (a) the rotation axis joining the centers of opposite faces (Fig. 10.3a), (b) the diagonal joining the opposite apices of the rhombohedron (Fig. 10.3b), and (c) the axis joining the centers of opposite rhombohedron edges (Fig. 10.3c).

The computational details (the optimization of LCAO basis and choice of cutoff energy in PW calculations, $\mathbf{k}$ -meshes used for BZ integration, choice of pseudopotentials) can be found in [715]. The advantage of PW calculations is that the complete optimization of lattice relaxation upon vacancy creation, even for large supercells, can be performed much faster than in LCAO calculations. Geometry optimizations in PW calculations have been carried out with an accuracy of 10^{-3} eV in the total energy. The electronic structure of defective SrTiO_3 perovskite calculated with both the CRYSTAL and VASP codes has been studied for the diamagnetic closed electronic shell (singlet) state, since no lower state was found employing spin-polarized calculations [713].

The basic properties of a perfect cubic SrTiO_3 crystal (lattice constant, bulk modulus, elastic constants) were obtained in reasonable agreement with experiment in LCAO calculations. The best agreement with experimental results for the energy gap was obtained for the hybrid HF–DFT technique (B3PW), see Chap. 9. Further improvement of the calculated optical gap was achieved by adding the d polarization orbital into the oxygen basis set: at the Γ point of BZ, the calculated gap 3.65 eV

Table 10.10 Dependence of the nearest distance between F centers (d_{F-F}), formation energy of a single oxygen vacancy $E_f(F)$, and energy barrier $E_{diff}(F)$ of its (011) diffusion on both shape and size of supercell used for PW calculations [715]

Supercell	Extension	Type of lattice	d_{F-F} (Å)	$E_f(F)(\text{eV})$		$E_{diff}(F)$ (eV)
				Unrelaxed	Relaxed	
S80	$2\sqrt{2} \times 2\sqrt{2} \times 2\sqrt{2}$	<i>fcc</i>	11.04	9.00	7.73	0.41
S135	$3 \times 3 \times 3$	<i>scc</i>	11.71	9.17	7.89	0.35
S160	$2\sqrt{3} \times 2\sqrt{3} \times 2\sqrt{3}$	<i>bcc</i>	13.52	8.98	7.35	0.50
S270	$3\sqrt{2} \times 3\sqrt{2} \times 3\sqrt{2}$	<i>fcc</i>	16.56	8.98	7.17	0.38

Table 10.11 Dependence of lattice relaxation for the nearest equivalent atoms around a single F center in a cubic SrTiO₃ crystal on shape and size of supercells in PW calculations [715]. Relative radial shifts from unrelaxed positions (%)* are given

Nearest atoms	Distance (in units of <i>a</i>)	Number of equiv. atoms	S80	S135	S160	S270	S320
Ti	1/2	2	7.21	7.16	7.08	8.28	7.76
O	$\sqrt{2}/2$	8	−7.59	−7.92	−7.98	−7.43	−7.79
Sr	$\sqrt{2}/2$	4	3.51	3.48	3.45	3.42	3.94
O	1.0	4	3.16	2.98	2.49	2.87	3.56
O	1.0	2	−1.72	−1.56	−1.67	−1.05	−1.28

* Positive shift corresponds to expansion of the atomic coordinate sphere, whereas negative sign means its compression

is close to the experiment, 3.25 eV for the indirect bandgap. In DFT (PW91) PW calculations, the structural parameters were again found to be quite reasonable, but the optical bandgap of 2.59 eV is an evident underestimate, typical for the DFT method.

The F center was modeled by removing an oxygen atom in the supercell (see Fig. 10.3). For estimation of the formation energy $E_f(F)$ of the F center, the energy for the spin-polarized isolated oxygen atom (^3P state) was taken, and (10.1) was used. A similar approach for the determination of $E_f(F)$ was used in [717]. In an alternative approach [709, 712], the formation energies of the O vacancy were expressed via chemical potentials of O, Sr, and Ti atoms. However, the range of $E_f(F)$ calculated using both approaches for supercells of different shapes and sizes is not so large as to give a preference to one of them.

Table 10.10 shows the dependence of the vacancy-formation energy in SrTiO₃ bulk on both supercell shape and size, which is accompanied by the large contribution coming from the lattice relaxation upon vacancy formation. The formation energy is reduced considerably (by 1.5–2.0 eV) when the positions of all atoms in the supercells are fully optimized. This demonstrates that the relaxation of even 14 nearest ions (neighboring Ti, O, and Sr coordination spheres directly shown in Fig. 10.3a) might be somewhat insufficient and the inclusion of next-nearest coordination spheres is necessary, see Table 10.11.

The lattice relaxation around the defect is periodically repeated in the supercell model, thus affecting the calculated total energy per cell: the larger the supercell, the smaller this artifact. The numerical results given in Tables 10.10 and 10.11 are obtained in PW calculations, as complete optimization of the lattice relaxation in the large supercells is extremely time consuming in the LCAO calculations.

The calculated defect-formation energies mainly decrease with the increase of the supercell size, but they also depend on the shape of the supercell (compare the corresponding values for fcc 80-atom and sc 135-atom cells). To calculate the energy barrier $E_{\text{diff}}(F)$ for oxygen-vacancy diffusion, a jump of the O atom from the eight possible sites nearest to the F center (Fig. 10.3a) toward the vacancy is considered. The saddle point energy has been estimated by fixing a hopping O atom at the middle of the Sr–Ti–Sr triangle (Fig. 10.3a) crossed by the oxygen migration trajectory, which has been found to be nonlinear, while the rest of the lattice has been allowed to relax to the minimum of the total energy. The $E_{\text{diff}}(F)$ (Table 10.10) is sensitive to both the shape and size of the SrTiO_3 supercell; moreover, for optimized rhombohedral *fcc* and *bcc* supercells (Fig. 10.3, b and c), the migration trajectories are not completely equivalent. Nevertheless, migration energies mainly decrease with increase of the supercell size. The sensitivity of the calculated lattice relaxation around the defect to both supercell shape and size is also clearly seen in Table 10.11. For the same type of superlattice (*sc*, *fcc*, or *bcc*), expansion of the first coordination sphere (two Ti ions) is larger, whereas compression of the second sphere (eight O ions) is smaller with increasing size of the supercell. However, the convergence of the lattice relaxation is complex, and a very low concentration of F centers should be used to achieve it. For instance, fcc supercells are stretched along the *z*-axis and are compressed in the *xy*-plane (Fig. 10.3b). This causes the larger *z*-shifts of Ti ions nearest to the O vacancy in 80- and 270-atomic *fcc* supercells, as compared with 135- and 320-atomic cubic supercells (Table 10.11), whereas *xy*-shifts of the nearest O and Sr ions are smaller in the former case. Nevertheless, the range of δR for equivalently shifted atoms in equidistant supercells of different shapes and sizes is small enough ($\leq 1.0\%$) to suggest the stabilization of a single O vacancy in a cubic SrTiO_3 crystal when using large equidistant supercells containing 270 and 320 atoms.

When trying to use the LCAO basis for partial optimization of the total energy for the same supercells, a markedly smaller expansion of the first coordination sphere involving the two nearest titanium ions as compared with complete optimization in PW calculations (1.5–2% vs. 7–8%) was obtained. The same is true for the next-nearest coordination spheres.

While use of the PW basis is more efficient for optimization of the lattice relaxation around a vacancy, the LCAO basis possesses a noticeable advantage when describing the electronic properties of defective crystals. To gain deeper insight into the defective SrTiO_3 bulk from LCAO calculations on different supercells in [715], the electron density due to O-vacancy formation was analyzed. Redistribution of the electron density due to O-vacancy formation is shown in Fig. 10.4 (a and b) as calculated for the equidistant fcc supercells with different extensions.

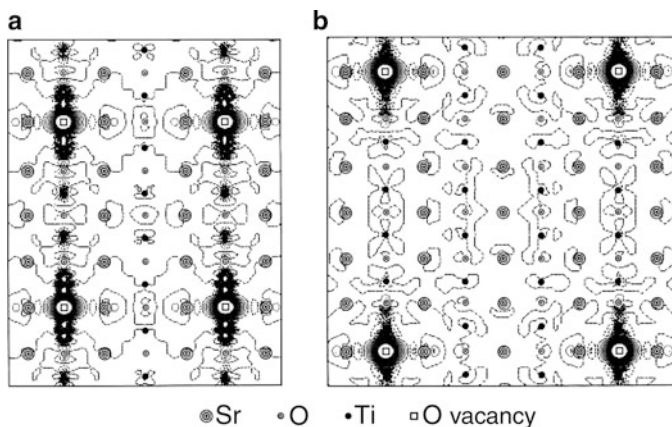


Fig. 10.4 Two-dimensional (2D) difference electron-density maps (the total density in the perfect SrTiO_3 bulk minus the sum of electron densities of both isolated oxygen atoms and defective SrTiO_3) projected onto the (110) section plane P-P for 80-atom (a) and 270-atom (b) fcc supercells containing a single oxygen vacancy [715]. *Dash-dot isolines* correspond to the zero level. *Solid and dashed isolines* describe positive and negative values of electron density, respectively. The isodensity increment is $0.002 \text{ e/\AA}^{-3}$.

In both plots, the Mulliken electron charge (1.1–1.3 e) is localized within a neutral O vacancy; in other words, $0.6\text{--}0.8 \text{ } e$ is equally divided by the two Ti ions nearest to the neutral F center and mainly localized on their $3d_{z^2}$ orbitals, making the largest contribution to the defect bands shown in Fig. 10.5 (a and b).

Figure 10.4 clearly demonstrates the effect of size of the *fcc*-type supercell (80 atoms and 270 atoms) on localization of the charge redistribution. For the 80-atom supercell, mutual interaction of the neighboring O vacancies is clearly seen, especially along the --Ti--O--Ti-- axes, whereas for the 270-atom supercell, the more or less visible redistribution of the electron density is limited by a region of 1.5–2.0 lattice constants around a vacancy, in the z -direction.

From Fig. 10.5 it is seen that the defect-band dispersion becomes very small for a 270-atom supercell demonstrating decreasing the defect–defect interaction. The latter is also manifested in LCAO calculations through the finite defect bandwidth. As noted earlier, a pure DFT (PW91) functional strongly underestimates the bandgap. As is seen from Table 10.12 (the results of LCAO calculations are given), the F-center energy level, remaining in the bandgap, approaches the conduction-band bottom, moving from 0.69 eV for the 80-atom supercell (with a bandwidth of 0.15 eV) down to 0.57 eV (0.08 eV) for 160 atoms, and finally reaching the optical ionization energy of 0.49 eV (almost neglecting the dispersion of 0.02–0.03 eV) for supercells of 270 and 320 atoms where the distance between the nearest defects is close to four lattice constants.

The results presented in Table 10.12 confirm that the 135-atom supercell is not big enough to reduce defect–defect interactions; its dispersion $\delta\epsilon$ is even larger than for an 80-atom supercell with a different shape, *that is*, $\delta\epsilon$ is sensitive to both the shape and size of the equidistant supercell, similar to other properties

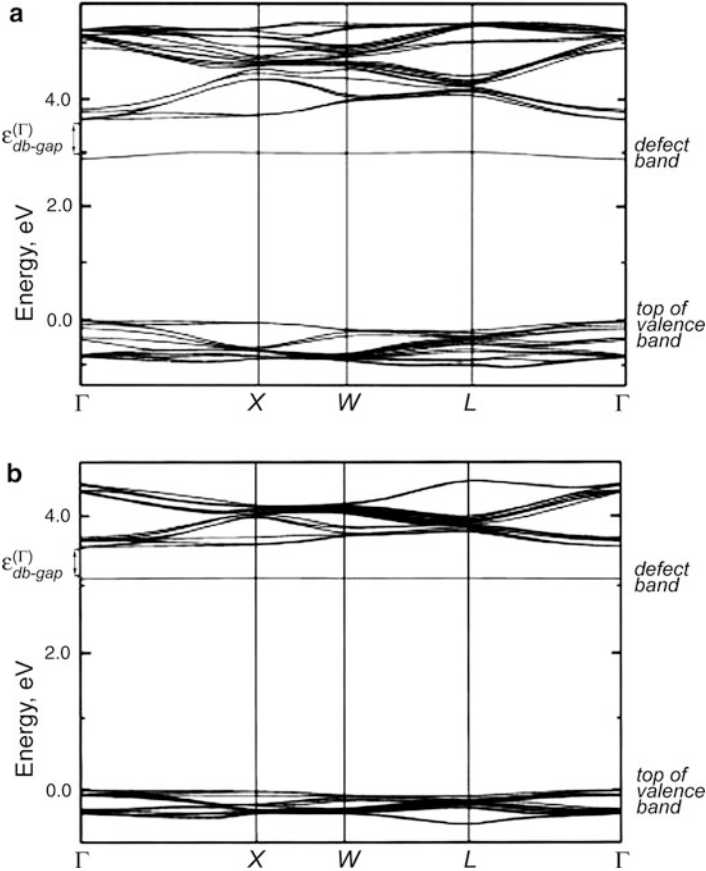


Fig. 10.5 Band structure of unrelaxed SrTiO_3 crystal with a single F center per fcc supercell containing either 80 atoms (**a**) or 270 atoms (**b**) [715]. Energy bands corresponding to the F center are split off the conduction bands. Their depth (gap) is shown relative to the bottom of the conduction band at the Γ point

Table 10.12 Dependence of the F-center energy-level position with respect to the conduction-band bottom of unrelaxed SrTiO_3 crystal with periodically distributed oxygen vacancies (ϵ), its dispersion ($\delta\epsilon$), and distance between the nearest F centers ($d_{\text{F-F}}$) as a function of the supercell size used in LCAO–B3PW calculations [715] with $2 \times 2 \times 2$ $\mathbf{k}$ -mesh*

Supercell	Extension	Type of lattice	$d_{\text{F-F}}$ ($\text{\AA}$)	ϵ	$\delta\epsilon$
S80	$2\sqrt{2} \times 2\sqrt{2} \times 2\sqrt{2}$	<i>fcc</i>	11.04	0.69	0.15
S135	$3 \times 3 \times 3$	<i>scc</i>	11.71	0.72	0.23
S160	$2\sqrt{3} \times 2\sqrt{3} \times 2\sqrt{3}$	<i>bcc</i>	13.52	0.57	0.09
S270	$3\sqrt{2} \times 3\sqrt{2} \times 3\sqrt{2}$	<i>fcc</i>	16.56	0.49	0.02
S320	$4 \times 4 \times 4$	<i>sc</i>	15.61	0.49	0.03

*The defect-level position is calculated at the Γ point of the BZ

described before. At the same time, the defect band for the 270-atom supercell (Fig. 10.5b) is almost a straight line. Table 10.12 clearly shows that the use of both supercells of 270 and 320 atoms practically eliminates the interaction between periodically distributed point defects.

The calculations [715] clearly demonstrate the advantage of combining DFT–PW and DFT–LCAO calculations. The former is necessary for the complete optimization of both lattice relaxation upon vacancy creation (especially for large supercells) and its migration, whereas the latter allows one to study in more detail the electronic structure for both unrelaxed and relaxed lattices. Such a combined study of the oxygen vacancy in SrTiO_3 crystal shows that achieving the convergence with the supercell increases up to 270–320 atoms, the defect–defect interaction becomes negligible, thus approaching a realistic model of a single F center. A similar conclusion follows from the study of the Fe impurities in SrTiO_3 , considered in next section.

10.3.2 Supercell Model of Fe-Doped SrTiO_3

The properties of transition-metal impurities, especially iron, in ABO_3 perovskite ferroelectrics are of considerable interest due to their photochromic, photorefractive, and other applications.

There were several theoretical calculations for ion impurities substituting for B atoms. Molecular-cluster calculations were made to study charged point defects in SrTiO_3 – $3d^3$ ions Cr^{3+} , Mn^{4+} , Fe^{5+} [724] and Fe^{3+} , Fe^{4+} , Fe^{5+} ions [725–727]. The formal charges used in designations of impurity ions mean the metal-atom oxidation state. As was already noted, the calculated charges on transition-metal atoms in perovskites differ essentially from the formal charges due to strong covalent interaction with oxygen atoms. Bearing in mind that in perfect SrTiO_3 crystal Ti^{4+} means the titanium-atom oxidation state 4, Fe^{3+} , Fe^{4+} , and Fe^{5+} ions can be considered as impurity centers with charges -1 , 0 , and $+1$, respectively. The supercell calculations are known for Fe impurities in KNbO_3 [728] in the LDA + U approximation, Li-doped KTaO_3 (semiempirical INDO simulations [729], and comparative DFT, PW, and INDO calculations [730]).

The supercell DFT–PW calculations of different donor and acceptor centers in SrTiO_3 [731] demonstrated the dependence of the formation energy on doping levels in the bulk crystal. In the majority of calculations cited, no lattice relaxation around the impurity was studied; the calculated density of states depends on the parameters used in the LDA + U or INDO approximations for the Hamiltonian.

A combination of first-principles supercell HF and DFT calculations that include lattice relaxations have been used in [664] to investigate the energy levels of neutral Fe^{4+} substitution on the Ti site. Here we consider these calculations in more detail. A consistent supercell–cyclic-cluster approach was applied for defective solids (see Sect. 10.1.3) with a focus on a detailed treatment of lattice relaxation around a single defect.

For a perfect crystal, results of periodic HF and DFT calculations based on LCAO approximation are compared. Despite the fact that the supercell approach is widely used in defect calculations, very little attention is paid to the supercell shape and size optimization and the effect of periodically repeated defect interaction. Following the method accepted for the above-considered supercell calculations of native point defects (interstitial oxygen in MgO, F center in Al_2O_3 and SrTiO_3), a study of the convergence of results to the limit of a single defect is one of the main emphases of the calculations [664] on Fe-doped SrTiO_3 . The transformation matrices for the supercells used are given in (10.14) in general form and define the equidistant supercells, forming sc, fcc, and bcc lattices. In the footnote to Table 10.13, actual transformation matrices used in Fe-doped SrTiO_3 calculations are given [664].

For the perfect crystal, the special $\mathbf{k}_q$ -point sets corresponding to these supercells satisfy the Chadi–Cohen condition, see (4.83):

$$\sum_{\mathbf{k}_q} W_q \sum_{|\mathbf{A}_j|=R_m} \exp(i\mathbf{k}_q \cdot \mathbf{A}_j) = 0, \quad m = 0, 1, 2, 3, \dots \quad (10.16)$$

where the second sum is over lattice vectors of the same length equal with the m th neighbor distance R_m , the first sum is over a set of these special $\mathbf{k}_q$ points, and W_q are weighting factors equal to the number of rays in their stars. The larger the number m , the better is the electronic-density approximation for the perfect crystal. The numbers M ($m = 0, 1, 2, \dots$), defined according to (10.16) the accuracies of the corresponding sets, are given in Table 10.13.

The *ab initio* periodic restricted and unrestricted HF (RHF, UHF) calculations were performed for perfect and defective SrTiO_3 crystals, respectively, using the CRYSTAL computer code [21]. This code has the option to perform both HF and DFT calculations on equal grounds, for a large number of implicitly or *a posteriori* used exchange–correlation functionals that permits one to analyze directly the relevant electron correlation effects keeping other computational conditions the same. The same LCAO basis set was used in the HF and DFT (PWGGA) calculations. Large-core Durand–Barthelat [468] for Ti and O atoms and Hay–Wadt small-core pseudopotentials [467] for Sr atoms were used. The impurity iron atoms were treated as all-electron atoms. The “standard” basis for Ti and O was taken from previous TiO_2 LCAO calculations [558], whereas that for Fe and Sr from [613] and the CRYSTAL code site [21], respectively. The outer Ti, Fe, and oxygen O basis functions were reoptimized. To characterize the chemical bonding and covalency effects for both defective and perfect crystals, a standard Mulliken population analysis was used for the effective atomic charges q and other local properties of electronic structure—bond orders, atomic covalencies, and full valencies (these local properties of electronic structure are defined in Sect. 9.1.2).

Since the lattice-relaxation calculations around a point defect was one of the aims, the band-structure calculations with the lattice constant a optimization were made for the perfect crystal. The values obtained were $a = 3.92, 3.84$, and 3.92 Å for HF, HF–PWGGA, and DFT–PWGGA, respectively. The experimental value is $a_0 = 3.905$ Å. The bulk moduli are $B = 222, 242$, and 195 GPa, respectively,

Table 10.13 Convergence of results for pure SrTiO₃ ($a = 3.905$ Å) obtained for pure HF (a) and DFT-PWGGA (b) LCAO band calculations corresponding to cyclic clusters of an increasing size [664]. All energies in eV, total energies are presented with respect to the reference point of 80 a.u. = 2176.80 eV. q , and V are effective atomic charges and valencies (in e), respectively. R_M and M are explained in the text

Supercell	Matrix	M	$R_M(\text{Å})$	$E_{\text{tot}}(\text{eV})$	V	C	$q(\text{Ti})$	$q(\text{O})$	$q(\text{Sr})$	$V(\text{Ti})$	$V(\text{O})$	$V(\text{Sr})$
(a) HF-LCAO calculations												
S8, <i>sc</i>	<i>A</i>	4	7.81	-24.288	-6.838	3.393	2.39	21.41	1.84	3.94	2.07	2.01
S16, <i>fcc</i>	<i>B</i>	7	11.04	-24.818	-6.895	3.766	2.54	21.46	1.84	3.97	2.06	2.01
S32, <i>bcc</i>	<i>C</i>	11	13.53	-24.873	-6.906	3.725	2.54	21.46	1.84	3.98	2.06	2.01
S64, <i>sc</i>	<i>D</i>	14	15.62	-24.873	-6.906	3.720	2.54	21.46	1.84	3.98	2.06	2.01
S108, <i>bcc</i>	<i>E</i>	24	20.29	-24.883	-6.895	3.744	2.54	21.46	1.84	3.98	2.06	2.01
(b) DFT-PWGGA-LCAO calculations												
S8, <i>sc</i>	<i>A</i>	4	7.81	-73.059	-4.647	4.367	3.43	21.74	1.79	3.98	2.06	2.04
S16, <i>fcc</i>	<i>B</i>	7	11.04	-73.024	-2.735	2.169	2.82	21.51	1.71	3.97	2.09	2.04
S32, <i>bcc</i>	<i>C</i>	11	13.53	-70.874	-2.737	1.219	2.55	21.42	1.70	3.99	2.11	2.04
S64, <i>sc</i>	<i>D</i>	14	15.62	-66.101	-2.414	0.027	1.69	21.13	1.70	4.12	2.18	2.04
S108, <i>bcc</i>	<i>E</i>	24	20.29	-66.134	-2.443	-1.025	1.69	21.13	1.70	4.12	2.18	2.04

Transformation matrices

$$A = \begin{pmatrix} 2 & 0 & 0 \\ 0 & 2 & 0 \\ 0 & 0 & 2 \end{pmatrix}, B = \begin{pmatrix} 2 & 2 & 0 \\ 2 & 0 & 2 \\ 0 & 2 & 2 \end{pmatrix}, C = \begin{pmatrix} 2 & 2 & -2 \\ 2 & -2 & 2 \\ -2 & 2 & 2 \end{pmatrix}, D = \begin{pmatrix} 4 & 0 & 0 \\ 0 & 4 & 0 \\ 0 & 0 & 4 \end{pmatrix}, E = \begin{pmatrix} 3 & 3 & -3 \\ 3 & -3 & 3 \\ -3 & 3 & 3 \end{pmatrix}$$

to be compared with the experimental value (extrapolated to 0 K) $B = 180$ GPa. That is, pure HF gives an error of 0.5% only for the lattice constant, and by 20%, overestimates the bulk modulus. Its *a posteriori* electron correlation correction, HF-PWGGA, gives too small a value, and B even larger than the pure HF. Use of an optimized basis set results in $a = 3.93, 3.85$, and 3.93 Å for HF, HF-PWGGA, and DFT-PWGGA, respectively. The relevant bulk moduli are $B = 220, 249$, and 191 GPa, respectively. That is, the basis optimization only slightly affected the calculated a and B values.

Table 10.13a and b demonstrate the effect of the cyclic-cluster increase for both HF and DFT-PWGGA methods, respectively. The main calculated properties are the total energy E_{tot} (per primitive unit cell), one-electron band-edge energies of the valence-band top and conduction-band bottom ε_v and ε_c , Mulliken effective atomic charges q , and full atomic valencies V . As is seen, the result convergence, as the supercell size increases, is quite different for the HF and DFT. We explain the much slower DFT convergence by a more covalent calculated electron-charge distribution, as compared to the HF case. For both methods, the convergence of local properties of the electronic structure is faster than that for the total and one-electron energies.

Based on the results of Table 10.13, the conclusion can be drawn that in the HF-LCAO calculations of a perfect crystal, the electronic structure is reasonably well reproduced by the supercell of 80 atoms ($L = 16$). This is confirmed by the band-structure analysis. The results of the standard band-structure calculations for

Table 10.14 The width of the Fe impurity band E_W calculated for the relevant supercells

Supercell	Number of atoms	Fe–Fe distance (Å)	E_W (eV)
S8	40	7.81	1.42
S16	80	11.04	0.23
S32	160	13.53	0.14

the SrTiO_3 primitive unit cell with Monkhorst–Pack k -set $6 \times 6 \times 6$ and the cyclic cluster of 80 atoms (only at the Γ point of the BZ) are very similar. It appears that the most important features of the electronic structure of a perfect crystal (valence and conduction bandwidths, local properties of electronic structure) are well reproduced by the cyclic cluster of 80 atoms. The corresponding one-electron energies do not practically change along all the symmetry directions in the narrowed BZ for supercell band calculations.

Analysis of the difference electron-density plots, calculated for the band and the 80-atom cyclic-cluster calculations, confirms that the latter well reproduces the electron-density distribution in a perfect crystal. Lastly, the total and projected density of states for a perfect crystal show that the upper valence band consists of O $2p$ atomic orbitals with admixture of Ti $3d$ orbitals, whereas the Sr states contribute mainly to the energies close to the conduction-band bottom, in agreement with previous studies.

However, as follows from Table 10.13, very accurate modeling of pure SrTiO_3 by means of DFT–PWGGA needs use of cyclic clusters as large as 320 atoms ($L = 64$). This conclusion agrees with the results of DFT–PW supercell calculations on SrTiO_3 discussed in the preceding subsection.

Table 10.13 has shown that an increase of the cyclic cluster from S16 to S32 does not change the HF-calculated top of the valence band. However, the calculated width of the defect impurity band E_W found using a standard Monkhorst–Pack set $6 \times 6 \times 6$ for three different supercells (Table 10.14) demonstrates clearly a considerable dispersion of defect energies across the supercell BZ.

Indeed, the E_W decreases rapidly, from 1.42 eV (S8) down to 0.23 eV (S16) and further down to 0.14 eV (S32), when the Fe–Fe distance increases only by a factor of about 2, from 7.81 to 13.53 Å, since an overlap of the impurity atomic functions decreases exponentially. This is why only S32 (160-atom cyclic cluster) is suitable for a careful modeling of the single Fe impurity and lattice relaxation around it. This is in contrast to many previous supercell calculations of defects in perovskites where S8 supercells were often used without any convergence analysis.

Mulliken effective charges calculated for ions at different positions in supercells modeling pure and Fe-doped SrTiO_3 are summarized in Table 10.15.

Table 10.15 demonstrates that the standard band-structure calculation and the S64 cyclic cluster give essentially identical charges. The more so, charges of the same ions in a 320-atom supercell are the same, irrespective of the ion position inside the cyclic cluster. Next, in the defective-crystal calculations, say, for the S32 cyclic cluster, the effective charges of atoms close to its boundary are the same as in the perfect crystal. This confirms that the chosen cyclic cluster is large enough.

Table 10.15 Effective charges q of ions obtained in the HF band-structure calculations with a Monkhorst–Pack k -set $6\times 6\times 6$ and different cyclic clusters modeling perfect and defective SrTiO_3 . The lengths in the first column are lattice constants of the relevant supercells; the distances R given above the effective charges are calculated with respect to the supercell coordinate origin where the Fe ion is placed

R (Å)	0.00	1.95	3.38	3.90	4.37	5.52	5.86	6.48	6.76	7.04	7.81
Lattice const.(Å)	$q(\text{Fe})$	$q(\text{O})$	$q(\text{Sr})$	$q(\text{Ti})$	$q(\text{O})$	$q(\text{Ti})$	$q(\text{O})$	$q(\text{Sr})$	$q(\text{Ti})$	$q(\text{O})$	$q(\text{Ti})$
3.90 (Band struct.)		−1.458	1.837	2.538							
15.62 (S64)											
(Perfect cryst.)		−1.459	1.837	2.540	−1.459	2.540	−1.459	1.837	2.540	−1.459	2.540
7.81 (S8)	2.583	−1.464	1.835	2.406							
11.04 (S16)	2.571	−1.464	1.840	2.536	−1.460	2.543					
13.53 (S32)	2.570	−1.464	1.838	2.534	−1.458	2.540	−1.459	1.837	2.540		
15.62 (S64)	2.570	−1.463	1.838	2.534	−1.458	2.540	−1.459	1.837	2.540	−1.459	2.539

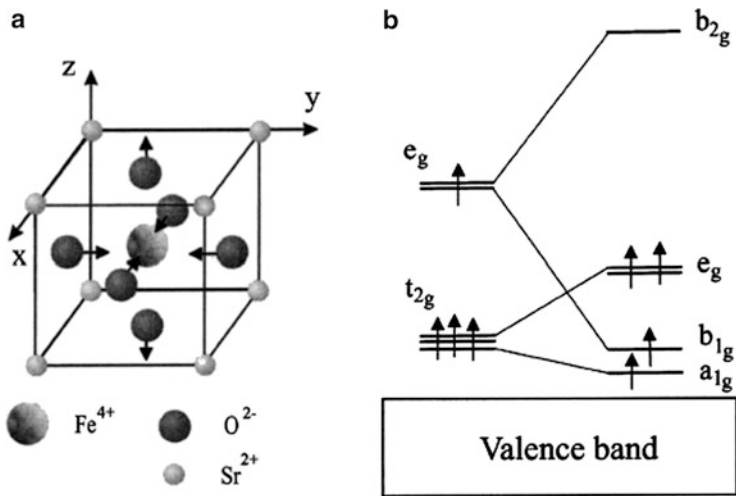


Fig. 10.6 (a) Schematic view of the Fe impurity with asymmetric e_g relaxation of the six nearest O atoms. (b) The relevant energy levels before and after relaxation

The S32-UHF supercell calculations for the zero-spin and high-spin ($S = 2$) states show that the latter is much lower in energy (by 5.4 eV) (after lattice relaxation). In the perovskite crystalline field, a fivefold degenerate Fe $3d$ state splits into e_g and t_{2g} states (see Fig. 10.6) separated by 2.1 eV (for an undistorted lattice). In the high-spin state with $S = 2$, the upper level is occupied by one α electron, and three other α electrons occupy t_{2g} states. As is well known in this case, an $E_g \otimes e_g$ Jahn–Teller effect takes place. This means that an orbital degeneracy is lifted by an asymmetrical displacement of six O ions, as shown in Fig. 10.6: four equatorial O atoms lying in the xy -plane relax toward the impurity, whereas the two

Table 10.16 Positions of one-electron Fe levels (in eV) with respect to the valence-band top calculated by means of HF method for S16 (80 atoms) and S32 (160 atoms) cyclic clusters with and without lattice relaxation

Cyclic cluster	Before relaxation		After relaxation			
	t_{2g}	e_g	a_{1g}	b_{1g}	e_g	b_{2g}
80 atoms	0.36	2.31	0.02	0.03	0.5	5.4
160 atoms	0.25	2.50	0.02	0.05	0.5	5.0

Table 10.17 The effective Mulliken charges of atoms q and bond orders W (in e) for S32 HF cyclic cluster with unrelaxed and relaxed lattices

SrTiO ₃	$q(\text{Ti})$	$q(\text{O}_{x,y})$	$q(\text{O}_z)$	$W(\text{Ti}-\text{O}_x)$	$W(\text{Ti}-\text{O}_z)$
Pure	2.540	-1.459	-1.459	0.375	0.375
Fe-doped	$q(\text{Fe})$	$q(\text{O}_{x,y})$	$q(\text{O}_z)$	$W(\text{Fe}-\text{O}_x)$	$W(\text{Fe}-\text{O}_z)$
Unrelaxed	2.570	-1.464	-1.464	0.164	0.164
Relaxed	2.594	-1.440	-1.534	0.235	0.154

other O atoms relax outward along the z -axis. This results in two nondegenerate levels close to the valence-band top: the e_g level at 0.5 eV above the band edge and a virtual nondegenerate b_{2g} level lying much higher (Table 10.16).

If we assume that x , y , and z displacements have equal magnitudes, pure HF and HF-PWGGA calculations with the “standard” basis set give practically the same magnitude of the six O displacements $\delta = 0.04$ Å, a quite flat minimum and an energy gain of 1.40 eV. This means that we have a combination of the Jahn–Teller and breathing modes of surrounding O atom displacements. With the optimized basis set, a slightly smaller energy gain 1.33 eV was obtained. It was checked also whether the magnitudes of the O atom displacements along the x , y , and the z axes could be different, and indeed, a small additional energy gain, down to 1.42 eV for the following asymmetrical displacements in the latter case, was found: 0.028 Å along the x and y axes and -0.052 Å along the z axis, *that is*, outward displacements of two O atoms are twice larger than those for four equatorial O atoms. Note that UHF calculation effectively incorporates the spin-dependent electron correlation effects during the self-consistent loops and thus gives nearly the same results as HF with *a posteriori* (nonself-consistent) corrections for electron correlations. The total valence of the iron impurity $V_{\text{Fe}} = 3.3$ correlates much better with the Fe^{4+} model than with the calculated Mulliken effective charge of $+2.59$. These effective charges q of atoms collected in Table 10.17 demonstrate considerable covalency effects, well known for ABO₃ perovskites.

In particular, in pure SrTiO₃, the effective charges are $q(\text{Ti}) = +2.54$, $q(\text{Sr}) = +1.84$, and $q(\text{O}) = -1.46$. The Ti–O bond order in a pure crystal is 0.375. When the two O atoms are displaced outward from the Fe impurity along the z axis and thus approach the nearest Ti atoms, the Ti–O bond order increases to 0.489. The combination of a large lattice-relaxation energy and relatively small O displacements is not surprising in the light of a considerable covalent bonding between the unpaired iron electrons occupying Fe $3d$ orbitals and $2p$ orbitals of

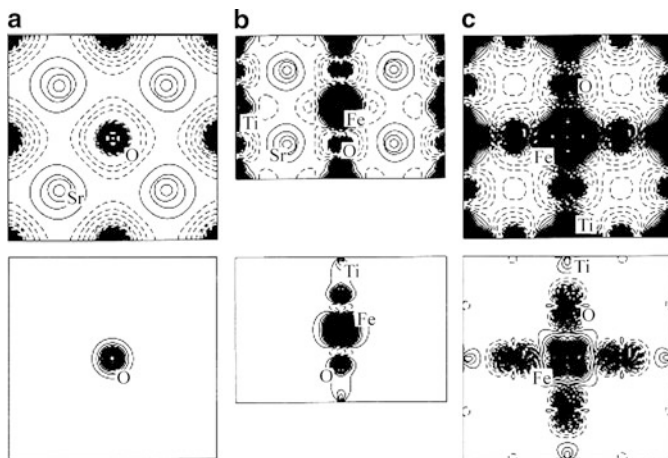


Fig. 10.7 (a) The electronic-density plots for the (010) cross section of Fe and nearest ions in SrTiO_3 as calculated by means of the HF method for the cyclic cluster of 160 atoms. Isodensity curves are drawn from 20.8 to $0.8 e \text{ a.u.}^{-3}$ with an increment of $0.0022 e \text{ a.u.}^{-3}$, (b) the same as (a) for the (001) section, and (c) the same for the (110) section. *Left panels* are HF difference electron densities; *right panels* are spin densities

four equatorial oxygen ions: the $\text{Fe-O}_{x,y}$ bond orders (Table 10.17) increase upon mutual approach of these atoms from 0.164 to 0.235.

Analysis of the total electron-density and spin-density distribution (Fig. 10.7) shows that in the HF calculation four unpaired electrons are well localized on the Fe ion.

Lastly, a comparison of the band structures for the cyclic cluster containing the Fe impurity with that for a pure crystal clearly demonstrates that the Fe impurity induces additional energy levels below the valence band (in the region around -20 eV) and above the valence band, at around -2 eV . These bands have practically no dispersion over the BZ, which demonstrates that the defect is almost isolated from its periodic images.

Any method is not completely universal, and the approach described also has its limitations. In particular, it does not work when incorporation of the lattice relaxation qualitatively changes the electron localization (*e.g.*, for free electron and hole polarons). On the other hand, it could be very efficient for many impurities in insulators characterized by high symmetry and when calculating forces is computationally expensive.

It was demonstrated that the size of the cyclic cluster large enough for a correct reproduction of the perfect crystal depends on the particular quantum-mechanical method; for SrTiO_3 , this means 80-atom cyclic clusters for the HF but 320 atoms for the DFT-PWGGA. In the HF defect calculations for the single Fe^+ impurity, the cyclic cluster should not be smaller than 160 atoms. This is in contrast with many previous supercell calculations on perovskites where supercells as small as S8 were used without convergence analysis.

It was already mentioned in Chap. 9 that the HF method typically overestimates the optical gap, whereas DFT underestimates it. This can affect the electronic-density distribution (chemical-bond covalency) and defect-level positions within the gap (even determined with respect to the valence-band top). In this respect, the hybrid HF–DFT methods widely used in the molecular chemistry, *for example*, B3LYP, seem to be more promising tools.

The calculations [664] have demonstrated the strong covalent bonding between unpaired electrons of Fe impurity and four nearest O ions relaxed toward an impurity. The positions of Fe energy levels in a SrTiO_3 gap are very sensitive to the lattice relaxation that was neglected in previous studies. The predicted positions of the Fe energy levels with respect to the valence-band top could be checked by means of UPS spectroscopy, whereas the local lattice relaxation around iron and its spin state was checked by means of EXAFS. The results of the calculations under consideration are important since the single Fe^{4+} ions were not detected by ESR (only Fe^{4+} –O vacancy complexes were experimentally studied) and their optical absorption bands at 2.1 and 2.8 eV [732] are tentative. Note that the high-spin state of Fe^{4+} impurity predicted in *ab initio* calculations contradicts previous semiempirical and nonself-consistent calculations (X_α – FeO_6 cluster calculation [725] and tight-binding calculation [726]). On the other hand, a high-spin state is indirectly supported by its observation for host Fe ions in SrFeO_3 perovskite.

We conclude this chapter by discussion of the supercell use for the solid-solution modeling. In this case, the supercells of different size allow different percentages of doping in solid solution to be modeled.

10.3.3 Modeling of Solid Solutions of $\text{La}_c\text{Sr}_{1-c}\text{MnO}_3$

One of the extensively studied perovskite-type materials, $\text{La}_c\text{Sr}_{1-c}\text{MnO}_3$ (LSM), is of special interest due to numerous applications, particularly as the cathode for solid oxide fuel cells [733].

LSM was investigated both theoretically [734, 735] and experimentally [736] with a focus on the chemical-bonding nature, magnetic properties, metal–insulator transitions, structural transformations, and surface properties.

Numerous efforts were undertaken to study the phase transformations and phase stability in LSM in a wide range of solid solutions. These materials exhibit a complicated dependence of the properties on the concentration of the Sr dopant and oxygen nonstoichiometry. Nowadays, it is well recognized that the dielectric, piezoelectric, and other LSM properties are entirely related to the phase equilibrium and the phase separation that occurs under different thermodynamic conditions.

In what follows we discuss the results of *ab initio* supercell studies of the relative stability of different LSM phases [737]. To perform the *ab initio* calculations, the program packages WIEN-2k (<http://www.wien2k.at>) and CRYSTAL-03 [21] were used.

The spin-polarized DFT FPLAPW and LCAO electronic and atomic-structure calculations [737] use the exchange–correlation PBE functional.

The basis set of augmented plane waves combined with local orbitals (APW + lo) is used in the WIEN-2k code for solving the Kohn–Sham equations. In this method the unit-cell volume is divided into two regions: (I) nonoverlapping atomic spheres centered at the atomic sites and (II) an interstitial region. In the two types of regions, different basis sets are used. Inside atomic sphere i of radius R_i , where electrons behave as they were in a free atom, a linear combination of radial functions times spherical harmonics is used. In the interstitial region between these atomic spheres, where the electrons are more or less “free,” a plane-wave expansion is used. On the sphere boundary, the wavefunctions of both regions are matched by a value. The APW + lo basis set has a significantly smaller size than the basis set in the LAPW method, and thus the computational time is drastically reduced. Nevertheless, these two schemes converge practically to identical results. The convergence of the method is controlled by a cutoff parameter $R_{\text{mt}}K_{\text{max}}$, where R_{mt} is the smallest atomic sphere radius in the unit cell and K_{max} is the magnitude of the largest $\mathbf{k}$ -vector in the reciprocal space. To improve the convergence of the calculations, it is necessary to increase this product. A reasonably large R_{mt} can significantly reduce the computational time. A value of $R_{\text{mt}} = 1.7$ a.u. was chosen, and a plane-wave cutoff $R_{\text{mt}}K_{\text{max}} = 9$.

The calculations [737] are performed for the high-temperature cubic phase of LaMnO_3 (LMO)-based crystals doped with Sr, substituting for La atoms in different fractions. This substitution results in a charge-compensating hole formation. The formation of other defects like oxygen or metal vacancies is neglected.

To model the LaMnO_3 doped by Sr (LSM), a $2 \times 2 \times 2$ supercell is used, which consists of eight primitive unit cells and thus contains 40 atoms. The WIEN-2k code generates the $\mathbf{k}$ -mesh in the irreducible wedge of the Brillouin zone (BZ) on a special-point grid that is used in a modified tetrahedron integration scheme (500 $\mathbf{k}$ -points were used). The accuracy in total energy calculations was 10^{-4} Ry. Different configurations of Sr atoms substituting for La atoms allow ordered LSM solid solutions to be modeled. In particular, $\text{La}_{0.875}\text{Sr}_{0.125}\text{MnO}_3$ is typically used in fuel cells and thus is the subject of detailed thermodynamic study. The calculations are carried out for the ferromagnetic spin alignment (all Mn spins in the supercells are oriented in parallel), which results in a metallic character of the resistivity [736]. However, the resistivity of this phase is larger by three orders of magnitude than that of a typical metal. This is confirmed by FP–LAPW band-structure calculations: a very small density of states (DOS) in the vicinity of the Fermi level is observed. The model used is in agreement with the calculations [735] where the ferromagnetic state was revealed for layers of a cubic $\text{La}_{0.7}\text{Sr}_{0.3}\text{MnO}_3$.

In [737], DFT–B3LYP–LCAO calculations for $\text{La}_c\text{Sr}_{(1-c)}\text{MnO}_3$ mixed crystals ($c = 0, 0.125, 0.5, 1.0$) were performed, see Fig. 10.8. La, Sr, and Mn core electrons were described by Hay–Wadt small-core (HWSC) pseudopotentials [467]. For the oxygen atoms, an all-electron 8-411(1d) G basis was taken from previous MnO calculations [612], performed with basis-set (BS) optimization. For La, Mn, and Sr ions, BSs 411(1d) G , 411(311d) G , and 311(1d) G were taken from La_2CuO_4 [738] calculations, the CRYSTAL web site [21], and SrTiO_3 calculations [590], respectively.

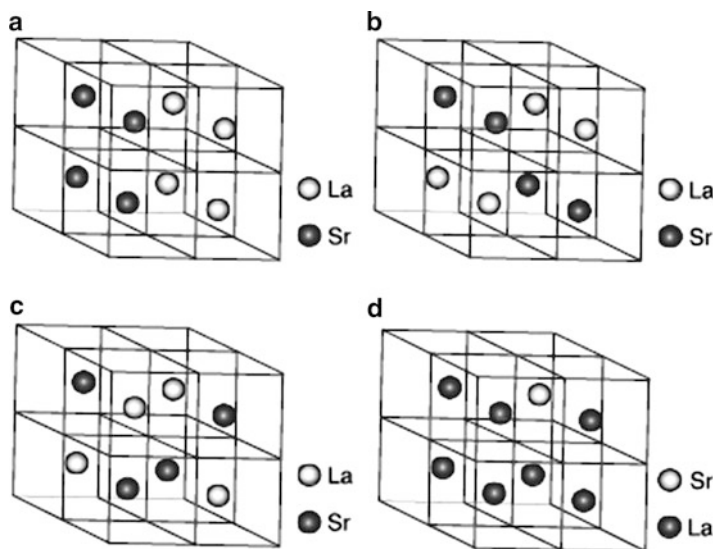


Fig. 10.8 Four structures used in calculations of $\text{La}_x\text{Sr}_{1-x}\text{MnO}_3$

To achieve a high numerical accuracy in the lattice and in the BZ summations, the cutoff threshold parameters of the CRYSTAL03 code for Coulomb and exchange integrals evaluation to 7, 7, 7, 7, and 14, respectively, were taken. The integration over the BZ has been carried out on the Monkhorst–Pack grid of shrinking factor 8 (its increase up to 16 gave only a small change in the total energy per unit cell). The self-consistent procedure was considered as converged when the total energy in the two successive steps differs by less than 10^{-6} a.u.

As the first step, B3LYP spin-polarized LCAO calculations for the cubic LaMnO_3 and SrMnO_3 (with one formula unit per primitive cell) are performed, using the maximal spin projection $S_z = 2$ for four d -electrons of the Mn^{3+} ion. As we have seen in Chap. 9, such a spin projection ensures the lowest total energy compared with $S_z = 0, 1$. The optimized cubic lattice constants are $a = 3.967 \text{ \AA}$ and $a = 3.840 \text{ \AA}$ for LaMnO_3 and SrMnO_3 , respectively. These values are in a reasonable agreement with the experimental lattice constants $a = 3.947 \text{ \AA}$ and $a = 3.846 \text{ \AA}$, respectively. The two optimized cubic lattice constants for LaMnO_3 and SrMnO_3 were used for calculating the lattice constants of their solid solutions according to Vegard's law (linear dependence of the lattice parameters on the composition). As follows from the WIEN-2k calculations, this is fulfilled quite well in this system.

To predict the relative stability of different phases, which might appear in the quasibinary phase diagram of LSM solid solutions in a wide range of dopant concentrations, the statistical thermodynamic approach combined with the *ab initio* calculations was used. Such an approach has been successfully applied to different systems (see, e.g., [739–741] and references therein).

Table 10.18 Total energies E_{tot} per $2 \times 2 \times 2$ cell, for $\text{La}_c\text{Sr}_{1-c}\text{MnO}_3$ compositions and equilibrium lattice parameters a_{eq} for different structures, see [737] and Fig. 10.8

Structure	c	WIEN-2k		Crystal-03	
		E_{tot} (Ry)	a_{eq} (Å)	E_{tot} (Ry)	a_{eq} (Å)
a	0.5	−115574.4034	3.881	−5771.8383	3.903
b	0.5	−115574.4248	3.881	−5771.8688	3.903
c	0.5	−115574.4178	3.879	−5771.8812	3.903
d	0.25	−94302.8877	3.862		
e	0.75	−136845.8880	3.901		
f	0.25	−94302.8725	3.865		
g	0.75	−136845.8763	3.901		
h	0.125	−83667.1051	3.855(3.828)*		
i	0.875	−147481.5822	3.914	−5776.8921	3.951
LaMnO_3		−158117.2795	3.921(3.947)*	−5778.3816	3.967
SrMnO_3		−73031.3269	3.848(3.806)*	−5764.9568	3.840

*For the references to these experimental data see in [737]

The standard periodic *ab initio* approach could be used only for ground-state energy calculations and ordered structures and thus does not allow prediction of thermodynamic stability of these phases as the temperature grows. This forces the problem to be reformulated so as to permit the extraction of the necessary energy parameters from the calculations for the ordered phases, and to apply these parameters to the study of the disordered or partly ordered solid solutions, in order to get information on the thermodynamic behavior of LSM solid solutions. From the experimental data [742], it follows that in these solid solutions Sr atoms substitute for La at all atomic fractions, $0 < c < 1$. Therefore, it is possible to consider the LSM solid solution as formed by La and Sr atom arrays occupying the sites of a simple cubic lattice immersed in the external field of the remaining lattice of Mn and O ions. The thermodynamics of such solid solutions can be formulated in terms of the effective interatomic mixing potential, which describes the interaction of La and Sr atoms embedded into the field of the remaining lattice. The study is based on the calculation of the relative stabilities of different ordered LSM cubic phases.

Figure 10.8 illustrates four phases: three of them (a, b, c) correspond to $c = 0.5$; the last one (i) with $c = 7/8$ corresponds to 12.5% Sr-doped LaMnO_3 . The remaining phases in Table 10.18 are the same as those used in $\text{Ba}_c\text{Sr}_{(1-c)}\text{O}_3$ calculations [739].

In the concentration wave (CW) theory, [743] the distribution of atoms A in a binary A–B alloy is described by a single occupancy probability function $n(\mathbf{r})$. This is the probability to find the atom A (La) at the site $\mathbf{r}$ of the crystalline lattice. The configurational part of the free energy of solid-solution formation (per atom) includes the internal formation energy ΔU , the function $n(\mathbf{r})$, a concentration of particles La(A), and the effective interatomic potentials between La atoms (A) and Sr atoms (B), for details see [737].

Table 10.19 Formation energies of different superstructures (in eV per atom on La/Sr sublattice) as calculated by means of the WIEN-2k (FPLAPW) and CRYSTAL-03 (LCAO) codes [737]

Configuration	FPLAPW	LCAO
a	0.170	0.288
b	0.207	0.339
c	0.195	0.360
i	0.080	0.320

To find the internal formation energies, which are differences between total energies of superstructures and the reference-state energy, the energy of a heterogeneous mixture, $c\text{LaMnO}_3 + (1-c)\text{SrMnO}_3$, has been chosen for the reference state. This energy is calculated as the sum of weighted (according to the atomic fractions) total energies of the two pure limiting phases, LaMnO_3 and SrMnO_3 . From *ab initio* calculations, the total energies E_{tot} and equilibrium lattice constant for all superstructures are obtained, Table 10.18. The internal formation energies for ordered phases (Table 10.19) are calculated by the definition

$$\Delta U = E_{\text{tot}} - \left(c E_{\text{tot}}^{\text{LaMnO}_3} + (1 - c) E_{\text{tot}}^{\text{SrMnO}_3} \right) \quad (10.17)$$

All these energies calculated using two very different DFT methods (FPLAPW and LCAO) are negative, *that is*, the formation of these ordered phases is energetically favorable with respect to their decomposition at $T = 0$ K into a heterogeneous mixture of LaMnO_3 and SrMnO_3 phases. It is easy to see from Table 10.18 that at the stoichiometric composition $c = 1/2$, the ordered phases a, b, and c (which have different local impurity arrangements in the supercell) are energetically more favorable than other phases. Also, these three phases differ slightly between themselves in the formation energies.

The absolute values for formation energies, given in Table 10.19, are larger in LCAO calculations than those from FPLAPW calculations, especially for the “i” configuration. In order to check this point, additional LCAO calculations were performed using two different hybrid exchange–correlation functionals (B3LYP and B3PW) and optimized lattice constants in all four configurations. However, the results are very close to those obtained by using Vegard’s law. Therefore, the only reason for the energy discrepancy is the use of different computational schemes. However, the use of two different methods allows more reliable information to be obtained. In this particular case, both methods give qualitatively similar results. Using these formation energies, it is possible to calculate the temperature evolution of the long-range order (LRO) parameters of the superlattices. The LRO parameters characterize the atomic ordering in sublattices of the ABO_3 -type perovskite. Their values were taken to be equal to unity (which corresponds to completely ordered phases at stoichiometric compositions). The concentration was taken to be equal

to the stoichiometric compositions of the corresponding phases. Finally, the free energy of formation of the phase $\text{La}_{0.875}\text{Sr}_{0.125}\text{MnO}_3$ was calculated (we refer the reader to [737] for details).

The calculations of LSM solid solution considered here demonstrate the efficiency of use of thermodynamic formalism based on combination of the *ab initio* electronic-structure calculations as developed in [737, 739–741]. The main feature of this approach is the treatment of ordered superstructures presenting the La–Sr sublattice immersed in the field of the remaining lattice formed by Mn and O atoms. The total energy calculations allow the formation energies of these superstructures for different compositions to be found, and their competition at $T = 0$ K to be analyzed. These calculations for a series of ordered structures permit extraction of the key energy parameters—the Fourier transforms of the mixing potential, and thus the free energy for temperature-induced partly disordered structures to be determined. Using the 12.5% Sr-doped LaMnO_3 , a thermodynamic analysis was performed [737]. It was predicted, in particular, that disordering of this phase with respect to the decomposition into the heterogeneous mixture of LaMnO_3 and SrMnO_3 can occur only at temperatures above the melting point. This is in contrast to a similar study of isostructural $\text{Ba}_c\text{Sr}_{(1-c)}\text{TiO}_3$ solid solution where below a certain temperature Ba impurities in SrTiO_3 tend to form BaTiO_3 nanoclusters.

In this chapter we have seen that in modern quantum chemistry of solids the first-principles periodic calculations are successfully extended to formally aperiodic systems—defective crystals and solid solutions. In the next chapter we consider the application of periodic models in the calculations of crystalline surfaces and adsorption.

Chapter 11

Surface Modeling in LCAO Calculations of Metal Oxides

In this chapter the capacity of LCAO methods in surface modeling is illustrated with numerous results of recent LCAO calculations. To model the electronic structure of surface states of crystals, three basic approaches are used: the cluster, slab (single and periodic), and semi-infinite crystal models. In the *single-slab* model, a crystal with a surface is approximated by a slab of finite thickness. The symmetry group of this model (diperiodic or layer group) allows the existence of symmetry operations that move the atoms out of the plane of the layer but bring them into positions occupied by other atoms of the slab. The results of the first-principles calculations of TiO_2 , SnO_2 , SrTiO_3 , SrZrO_3 , and LaMnO_3 surfaces are discussed.

11.1 Diperiodic Space Groups and Slab Models of Surfaces

11.1.1 Diperiodic (Layer) Space Groups

To model the electronic structure of surface states of crystals, three basic approaches are used: the cluster, slab (single and periodic), and semi-infinite crystal models. The latter is the most exact because it takes into account all the atoms of the crystal with a surface.

A *semi-infinite crystal* is a three-dimensional (3D) object. Its symmetry group contains, in addition to translations in the surface plane, only the rotations and mirror reflections that keep the atoms in the planes parallel to the surface. Only 17 such groups exist. Formally, these groups are isomorphic with diperiodic space groups in two dimensions. They are called *plane groups*.

In the *molecular-cluster* approach a crystal with a surface is modeled by a finite system consisting of the atoms on the surface and of some atomic planes nearest to it. The diperiodicity of the surface is not taken into account. The symmetry of such a model is described by one of the crystallographic point groups.

In the *single-slab* model a crystal with a surface is approximated by a slab of finite thickness. The symmetry group of this model allows the existence of symmetry operations that move the atoms out of the plane of the layer but bring them into positions occupied by other atoms of the slab. These are space diperiodic groups in three dimensions. They are also called the layer groups. We denote them by DG. These groups also describe the symmetry of thin films. In layered crystals the interaction between the nearest layers is usually weaker than that between nearest atoms in the same layer plane. Therefore, the slab model is a convenient approximation for such crystals. Layer groups describe the symmetry of this model. Diperiodic (layer) groups are the symmetry groups of three-dimensional (3D) objects with two-dimensional (2D) periodicity.

In plane-wave calculations the *periodic (repeated) slab* model is used. In this model the slab is periodically repeated along the normal to the slab surface plane. This repeating of the slab restores the 3D periodicity of the surface model. The symmetry group of the periodic slab is a space group (Chap. 2)—three-dimensional group with three-dimensional translations.

The layer groups DG belong to the so-called subperiodic groups. The latter include 7 frieze groups (two-dimensional groups with one-dimensional translations), 75 rod groups (three-dimensional groups with one-dimensional translations), and 80 layer groups (three-dimensional groups with two-dimensional translations). The information presented about the subperiodic groups in [744] is in the same format and consists of the same content as that provided in [19] for space groups G.

In [744] a relationship is considered between space and subperiodic groups: given a crystal of a specific space-group symmetry and a plane transecting the crystal, one can inquire as to what is the layer subgroup of the space group that leaves this plane invariant. The physical motivation for answering this question is clear as this problem arises, for example, in the surface modeling by a single slab. The information about subperiodic groups is followed in [744] by the scanning tables in which the layer symmetries of sectional planes are tabulated for all crystallographic orientations and for all positions (locations) of these planes. These tables also contain explicitly the orbits of these planes (an orbit is defined as a set of planes connected by the symmetry operations) and implicitly, via the so-called “scanning groups,” information about the rod symmetries of straight lines that penetrate through the crystal. Rod groups are used for studying polymers, nanotubes, and quantum wells.

Diperiodic group DG contains a subgroup of two-dimensional translations $T^{(2)}$ with elements $(E|\mathbf{a}_n)$, where

$$\mathbf{a}_n = n_1 \mathbf{a}_1 + n_2 \mathbf{a}_2 \quad (11.1)$$

is an arbitrary translation vector of the plane lattice and $\mathbf{a}_1, \mathbf{a}_2$ are unit-cell (primitive) translation vectors. The ends of all vectors $\mathbf{a}_n$ beginning at some origin O form a two-dimensional Bravais lattice. The point-symmetry group F_{DG} of this lattice must satisfy the following requirements: symmetry axes of order n (with $n > 2$) must be perpendicular to the plane of vectors $\mathbf{a}_1, \mathbf{a}_2$ (layer plane), and

reflection planes must be either perpendicular or parallel to this plane. These requirements restrict the number of possible two-dimensional lattices. The two-dimensional lattice of a layer group is also a two-dimensional lattice of a plane group (two-dimensional groups with two-dimensional translations). There exist five plane lattices, distributed over four crystal systems: oblique, rectangular (2 lattices—primitive and centered), square, and hexagonal.

The point symmetry of the oblique, rectangular, square, and hexagonal systems is given by C_2 , C_{2v} , C_{4v} , and C_{6v} point groups, respectively. Note that in a plane lattice, the inversion at the origin of the coordinate system is equivalent to the rotation through the second-order axis normal to the plane. Screw axes in layer groups may be only the second-order axes lying in the layer plane. Improper translations in operations of reflection in glide planes (parallel or perpendicular to the layer plane) must be oriented along the layer plane.

One can find the information about subperiodic groups on the Bilbao Crystallographic Server [16]. These groups are specified by their number as given in [744] or by the international symbols. The international symbol of layer group DG contains, first, the information about the plane Bravais lattice type: P (primitive) or C (centered). Then the information about symmetry elements is given. The screw axes (of second order) have the subscript 1. The reflection planes are denoted as follows: m (mirror planes), n, a, b (glide planes, depending on the direction of the improper translations). The subperiodic groups are described by means of a crystallographic coordinate system consisting of a crystallographic origin, denoted by O , and a crystallographic basis. The conventional basis vectors for the three-dimensional layer groups are labeled $\mathbf{a}$, $\mathbf{b}$, and $\mathbf{c}$. Unlike space groups, not all basis vectors of the crystallographic basis are lattice vectors (for primitive lattices, vectors $\mathbf{a}$ and $\mathbf{b}$ coincide with the primitive translations $\mathbf{a}_1$, $\mathbf{a}_2$). Like space groups, the crystallographic coordinate system is used to define the symmetry operations and the Wyckoff positions. The symmetry operations are defined with respect to the directions of both lattice $\mathbf{a}$, $\mathbf{b}$ and nonlattice $\mathbf{c}$ basis vectors. A Wyckoff position, denoted by a coordinate triplet (x, y, z) for the three-dimensional layer groups, is defined in the crystallographic coordinate system by $O + \mathbf{r}$, where $\mathbf{r} = x\mathbf{a} + y\mathbf{b} + z\mathbf{c}$.

Like space groups, the term setting will refer to the assignment of the labels $\mathbf{a}$, $\mathbf{b}$, and $\mathbf{c}$ (and the corresponding directions [100], [010], and [001], respectively) to the basis vectors of the crystallographic basis. In the standard setting, those basis vectors that are also lattice vectors are labeled for layer groups with their two-dimensional lattice by $\mathbf{a}$ and $\mathbf{b}$. The Wyckoff positions for the 80-layer groups can be found in [16, 744]. Note that the setting of the layer groups for rectangular lattices may be chosen different for the same group (symbols $P211$ and $P121$ refer to the same group in two different settings) but at the same time $P112$ and $P211$ denote different layer groups. In the first group, the axis of second order (oriented along the z -axis) is perpendicular to the layer plane; in the second, it lies in the layer plane xy and is directed along the x -direction. In the first case, the second-order axis is oriented along the plane translation lattice vector and, in the second case, along the nonlattice vector. Respectively, the Wyckoff positions for both groups are different, see [16].

Any element of the layer group may be written as $(R_i|v_i + a_n)$, where a_n and v_i are lattice and improper translations, $i = 1, 2$.

Let a_3 be a vector that does not lie in the layer plane. A set of elements $(E|n_3a_3)$ forms a group T_3 of one-dimensional translations. Consider the elements

$$(R_i|v_i + a_n)(E|n_3a_3), \quad (R_i|v_i + a_n) \in \text{DG}, i = 1, 2, \quad (E|n_3a_3) \in T_3 \quad (11.2)$$

The set (11.2) of symmetry operations contains a group of three-dimensional translations $(E|a_n + n_3a_3) \in T$. The set (11.2) is some space group provided the translational symmetry (the group T) is compatible with the point symmetry F_{DG} of the layer group DG . This condition is fulfilled if the vector a_3 is chosen perpendicular to the layer plane. Indeed, the translations $(E|a_n) \in T^{(2)} \subset T$ are compatible with F_{DG} as they are the elements of DG . The compatibility of the translations $(E|n_3a_3) \in T_3$ with point group F_{DG} follows from the fact that the rotations (proper and improper) from DG transform the layer into itself, and therefore, the vector perpendicular to the layer is transformed into a vector also perpendicular to the layer. Thus, the set of elements (11.2) forms one of the three-periodic space groups G . Moreover, the translational group T_3 is invariant in G : with the translation $(E|a_3)$, it contains also the translation $(E|R_i a_3)$ for any R_i from (11.2). Therefore, the group G may be expressed as a semidirect product

$$G = T_3 \wedge \text{DG} \quad (11.3)$$

and be decomposed into cosets with respect to T_3

$$G = \sum_i (R_i|v_i + a_n)T_3, \quad (R_i|v_i + a_n) \in \text{DG}, i = 1, 2 \quad (11.4)$$

Thus, subperiodic layer group DG is isomorphic to factor group G/T_3 . A relationship between factor groups of space groups and subperiodic groups is studied in [745, 746].

Table 11.1 gives correspondence $\text{DG} \leftrightarrow G/T_3$ between three-dimensional diperiodic (DG) and three-periodic (G) space groups. This correspondence was at first given by Wood [747] in the setting that differs for rectangular diperiodic groups from that given in Table 11.1 (the setting in this table corresponds to the standard setting of [744]). The layer and rod groups isomorphic to factor groups of space groups (the corresponding space groups are called reducible space groups) have been tabulated [746].

For some layer groups of oblique and rectangular crystal systems (DG 1, 2, 8–18), the vector a_3 may be inclined to the layer plane.

In the cases when a space group G may be represented as a semidirect product (11.3) in two different manners, it generates two nonisomorphic layer groups. For example, the layer groups $P112$ and $P211$ are related to one space group $P2(C_2^1)$ with two different settings (the second-order axis is oriented along the z - and x -directions, respectively). The space group $P2/b(C_{2h}^4)$ generates two-layer

Table 11.1 Correspondence between three-dimensional two-periodic (DG) and three-periodic (G) space groups (DG $\leftrightarrow$ G/ T_3), [744]

DG		G		DG		G		DG		G	
<u>1</u>	$P1$	C_1^1	1	28	$Pm2_1b$	C_{2v}^2	26	<u>55</u>	$P4mm$	C_{4v}^1	99
2	$P\bar{1}$	C_1^1	2	29	$Pb2_1m$	C_{2v}^2	26	<u>56</u>	$P4bm$	C_{4v}^2	100
<u>3</u>	$P112$	C_2^1	3	30	$Pb2b$	C_{2v}^3	27	57	$P\bar{4}2m$	D_{2d}^3	111
4	$P11m$	C_s^1	6	31	$Pm2a$	C_{2v}^4	28	58	$P\bar{4}2_1m$	D_{2d}^3	113
5	$P11a$	C_s^2	7	32	$Pm2_1n$	C_{2v}^7	31	59	$P\bar{4}m2$	D_{2d}^5	115
6	$P112/m$	C_{2h}^1	10	33	$Pb2_1a$	C_{2v}^5	29	60	$P\bar{4}b2$	D_{2d}^7	117
7	$P112/a$	C_{2h}^4	13	34	$Pb2n$	C_{2v}^6	30	61	$P4/mmm$	D_{4h}^1	123
8	$P211$	C_2^1	3	35	$Cm2m$	C_{2v}^{14}	38	62	$P4/nbm$	D_{4h}^3	125
9	$P2_111$	C_2^2	4	36	$Cm2a$	C_{2v}^{15}	39	63	$P4/mbm$	D_{4h}^5	127
10	$C211$	C_2^3	5	37	$Pmmm$	D_{2h}^1	47	64	$P4/nmm$	D_{4h}^7	129
<u>11</u>	$Pm11$	C_s^1	6	38	$Pmaa$	D_{2h}^3	49	<u>65</u>	$P3$	C_3^1	143
<u>12</u>	$Pb11$	C_s^2	7	39	$Pban$	D_{2h}^4	50	66	$P\bar{3}$	C_{3i}^1	147
<u>13</u>	$Cm11$	C_s^3	8	40	$Pmam$	D_{2h}^5	51	67	$P312$	D_3^1	149
14	$P2/m11$	C_{2h}^1	10	41	$Pmma$	D_{2h}^5	51	68	$P321$	D_3^2	150
15	$P2_1/m11$	C_{2h}^2	11	42	$Pman$	D_{2h}^7	53	<u>69</u>	$P3m1$	C_{3v}^1	156
16	$P2/b11$	C_{2h}^4	13	43	$Pbaa$	D_{2h}^8	54	<u>70</u>	$P31m$	C_{3v}^2	157
17	$P2_1/b11$	C_{2h}^5	14	44	$Pbam$	D_{2h}^9	55	71	$P\bar{3}12/m$	D_{3d}^1	162
18	$C2/m11$	C_{2h}^3	12	45	$Pbma$	D_{2h}^{11}	57	72	$P\bar{3}2/m1$	D_{3d}^3	164
19	$P222$	D_2^1	16	46	$Pmmn$	D_{2h}^{13}	59	<u>73</u>	$P6$	C_6^1	168
20	$P2_122$	D_2^2	17	47	$Cmmm$	D_{2h}^{19}	65	74	$P\bar{6}$	C_{3h}^1	174
21	$P2_12_12$	D_2^3	18	48	$Cmma$	D_{2h}^{21}	67	75	$P6/m$	C_{6h}^1	175
22	$C222$	D_2^6	21	<u>49</u>	$P4$	C_4^1	75	76	$P622$	D_6^1	177
<u>23</u>	$Pmm2$	C_{2v}^1	25	50	$P\bar{4}$	S_4^1	81	<u>77</u>	$P6mm$	C_{6v}^1	183
<u>24</u>	$Pma2$	C_{2v}^4	28	51	$P4/m$	C_{4h}^1	83	78	$P\bar{6}m2$	D_{3h}^1	187
<u>25</u>	$Pba2$	C_{2v}^8	32	52	$P4/n$	C_{4h}^3	85	79	$P\bar{6}2m$	D_{3h}^3	189
<u>26</u>	$Cmm2$	C_{2v}^{11}	35	53	$P422$	D_4^1	89	80	$P6/mmm$	D_{6h}^1	191
27	$Pm2m$	C_{2v}^1	25	54	$P42_12$	D_4^2	90				

The numbers of 17 plane groups are underlined.

groups $P112/a$ and $P2/b11$. In the first group the rotation axis is perpendicular to the layer, and the layer plane itself is a glide plane with an improper translation on a half-period along the x -direction. In the second group, the rotation axis is directed along the x -axis; the glide reflection plane is perpendicular to the layer (and to the rotation axis), and reflection in this plane is followed by improper translation on the half-period along the y -direction. The latter corresponds to the space group, with a nonconventional setting.

A particular case of layer groups is that of the so-called plane groups mentioned above. Formally, they are the symmetry groups of diperic systems in two dimensions. They correspond to the layer groups that do not contain the rotation axes lying in the layer plane and the reflection planes coinciding with the layer plane. Semi-infinite crystals with plane diperic surfaces have plane groups as the groups of symmetry.

The Wigner–Seitz (WS) cell for an arbitrary group DG is a right prism with a directrix lying in the layer plane. The projection of the Wigner–Seitz (WS) cell on the layer plane is a polygon constructed from the basis vectors $\mathbf{a}_1$ and $\mathbf{a}_2$ [13]. The WS cell of the corresponding triperiodic group G is derived by construction of additional planes perpendicular to the vectors $\mathbf{a}_3$ (and perhaps to their integer combinations with the vectors $\mathbf{a}_1$ and $\mathbf{a}_2$) and passing through their midpoints. Thus, the WS of the group G is a part of that for the corresponding group DG.

The site-symmetry groups of Wyckoff positions for the majority of positions belonging to both WS cells (of G and of DG) are identical since they are determined by the same set of symmetry operations. The only exception may be for the points on the sides of the group G cell that are absent in that of the group DG. The existence of translational symmetry in the third dimension in the group G may give rise to additional symmetry operations in site-symmetry groups for these points in the group G with respect to DG. The part of the WS cell of the layer group DG that has no common points with the cell of the corresponding group G contains the points of general position and the points with site symmetry defined by vertical planes and rotation axes. These types of site symmetry are already represented in the common part of the cells for G and DG. Therefore, the set of points with different types of site symmetry in the group G is larger than that in the group DG. Thus, the points of different types of site symmetry (Wyckoff positions) in DG may be specified by the same roman letters as in the corresponding groups G [16]. In layer groups, the inversion center and the points of intersection of vertical and horizontal symmetry elements may be situated only in the layer plane. This means that the symmetry points of the Wigner–Seitz cell for a layer group DG may appear only in its intersection with the layer plane. An example illustrating the Wyckoff positions connection in space group C_{2h}^5 and layer DG 18 is given in [13].

It can be shown that all the irreps of DG are contained in the irreps of the related space group G. The simple connection between the irreps of G and DG may be established using (11.3), *that is*, isomorphism $DG \leftrightarrow G/T_3$: every irrep of DG is related to a definite irrep of G (of the same dimension). In these irreps of G, all the elements of the coset $(R_i|\mathbf{v}_i + \mathbf{a}_n)T_3$ are mapped by the same matrix. In particular, all the translations in T_3 (coset $(E|\mathbf{0})T_3$) are mapped by unit matrices. We refer the reader to Chap. 6 in [13] for details. The same approach can be used to connect irreps of space group G with those of subperiodic rod group $RD \leftrightarrow G/T^{(2)}$ ($T^{(2)}$ is the two-dimensional group of translations in a plane that does not contain the one-dimensional translations of a rod group), [748]. The two-dimensional plane groups and the corresponding layer groups are isomorphic (see Table 11.1) and therefore have the same sets of irreps. The theory of induced reps described in Chap. 3 for triperiodic space groups G may be easily applied to diperiodic groups DG. The tables of simple induced reps of DG may be directly constructed by using this theory [13]. The induced reps of layer groups are useful when analyzing electron-density localization on a crystal surface. Such analysis is important in the study of chemisorption of atoms and molecules.

In order to understand the principal features of the origin of surface states, it is important to know how the energy bands of a crystal look in terms of the diperiodic

Table 11.2 Vectors of basis translations for three sections of a face-centered cubic Bravais lattice

Surface translation vectors	(001)	(110)	(111)
$\mathbf{a}_1$	110	-110	1-10
$\mathbf{a}_2$	1-10	002	10-1
$\mathbf{B}_1$	110	-110	2/3, -4/3, 2/3
$\mathbf{B}_2$	1-10	001	2/3, 2/3, -4/3

specification. The comparison of bulk and surface states according to the symmetry is based on the relation between the irreps of the corresponding tri- and dipericodic groups G and DG . The bulk states are specified by the wavevector $\mathbf{k}^{(3)}$ in the three-dimensional BZ (BZ-3) for the group G . The surface states are classified by $\mathbf{k}^{(2)}$ in the two-dimensional BZ (BZ-2) of the layer (plane) group DG . The choice of the translation vectors $\mathbf{a}_1$ and $\mathbf{a}_2$ in the surface plane defines its orientation relative to the primitive translation vectors $\mathbf{a}_i^{(3)}$ ($i = 1, 2, 3$) of the corresponding space group G . The surface is identified by three integers (hkl) —Miller indices, specifying the atomic planes in the crystal by means of the components of a vector perpendicular to that plane. Planes perpendicular to crystallographic axes X, Y, Z are indicated $(h00)$, $(0k0)$, and $(00l)$, respectively. In particular, the planes closest to the origin are identified with indices (100) , (010) , and (001) . Planes parallel to one of the three axes X, Y, Z are indicated $(0kl)$, $(h0l)$, and $(hk0)$, respectively. When the surface reconstruction effects (change of the surface plane translational symmetry with respect to that of the perfect crystal) may be neglected, the symmetry group DG of a crystal with a surface is a subgroup of the bulk-crystal group G . However, the BZ-2 depends on the indices of the surface plane.

Consider, for example, crystals with face-centered cubic Bravais lattices. For the (001), (110), and (111) sections, the plane lattices are square, rectangular, and hexagonal, respectively. The basic translation vectors of the direct and reciprocal lattices for these three cases are given in Table 11.2 ($\mathbf{a}_1$ and $\mathbf{a}_2$ are given in units $a/2$, $\mathbf{B}_i$ in units $2\pi/a$, where a is the cubic lattice parameter). Note that for a cubic lattice, the planes (100) , (010) , and (001) are equivalent. The equivalence takes place also for (110) , (101) , and (011) planes.

We see that the vectors $\mathbf{B}_i$ ($i = 1, 2$) are now not the translation vectors of the three-dimensional reciprocal lattice. Therefore, the boundaries of BZ-2 do not coincide with those of BZ-3.

Figure 11.1 shows the Brillouin zones corresponding to the surface (001), (110), and (111) inscribed in the three-dimensional Brillouin zone for a face-centered cubic lattice.

Note that some nonequivalent points of BZ-3 become equivalent in BZ-2 (e.g., the points X for the surface (001) and the points L for the (110) surface). Some points of BZ-2 have higher symmetry than in BZ-3 (e.g., the vertices of BZ-2 for the (111) surface). These properties of BZ-2 arise because the unit-cell vectors in the two-dimensional reciprocal space $\mathbf{B}_i$ are not the lattice vectors of the three-dimensional reciprocal lattice.

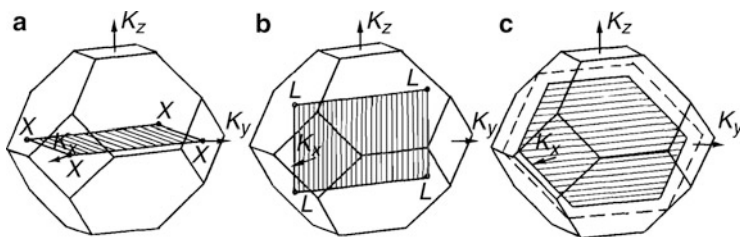


Fig. 11.1 Brillouin zones for a face-centered cubic lattice and surfaces (a) (001), (b) (110), (c) (111)

To obtain the crystal energy band structure in terms of a di-periodic specification, it is necessary to represent the dispersion law $E = E_n(\mathbf{k}^{(3)})$ in the form

$$E_n^s(\mathbf{k}_{\parallel}^s) = E_n(\mathbf{k}_{\parallel}^s + \mathbf{k}_{\perp} - \mathbf{B}_n) \quad (11.5)$$

where $\mathbf{k}_{\parallel}^s$ is a projection of the three-dimensional wavevector $\mathbf{k}^{(3)}$ onto the surface and $\mathbf{k}_{\perp}$ is its component perpendicular to the surface. The vector $\mathbf{B}_n$ is assumed to be chosen so that the wavevector $\mathbf{k}_{\parallel}^s = \mathbf{k}_{\parallel} + \mathbf{B}_n$ takes values in the limits of BZ-2. In the projection of the energy bands of the three-dimensional crystal on the two-dimensional Brillouin zone, forbidden energy lacunas can appear. When the surface is taken into account, a band of surface states appears inside the energy lacuna. These surface states are analogous to the local energy levels of point defects that appear in the forbidden energy gap of a perfect crystal. The energy levels of surface states may arise in the continuous energy spectrum of a bulk three-dimensional perfect crystal. These are the so-called resonance surface states. They are analogous to the point defect states in the spectrum of bulk-crystal states.

In the next sections we describe the slab models of the surface and illustrate the choice of the slab by examples of metal oxides with sodium chloride, rutile and cubic perovskite structures.

11.1.2 Oxide-Surface Types and Stability

Oxides are very common in nature and play a fundamental role in corrosion, friction, electronic devices, and superconductivity. The study of the properties of oxide surfaces has an interdisciplinary nature, being included in several fields of research—not only solid-state chemistry and physics, but also electrochemistry, catalysis, electronics, and even geophysics and geology. Nowadays, nanostructured surfaces are used as substrates for growing artificial structures, for example, to make quantum wires or size-controlled clusters.

The present understanding of oxide surfaces in the light of experimental and theoretical studies is summarized in books and review articles, see, for example,

[749–751]. Computer simulation plays an important role in the surface study and in recent decades has become an important tool for investigations of structural, electronic, and catalytic properties of surfaces. Computer simulation of surfaces is based on two key issues—model of the surface and the Hamiltonian used for the chosen model. Methodological developments and the rapid improvement of computer hardware have enabled theorists to work with systems of increasing complexity and apply *ab initio* (HF, DFT, and hybrid) Hamiltonians in the surface calculations. Thereby, it is possible not only to reproduce experimental findings with increasing accuracy, but it is also possible to help in the prediction and interpretation of experimental results. As for models, there were already mentioned both finite (molecular cluster and cyclic cluster) and infinite (semi-infinite crystal and slab) models. The model of a semi-infinite crystal is the most appropriate, because it takes into account an infinite number of atoms in the crystal below the surface. Slab and cluster models are, nevertheless, more popular, since they are more feasible from the computational point of view. The cyclic-cluster model is intermediate between the slab and molecular-cluster models. It takes into account the translational symmetry of the surface but considers only a finite number of interatomic interactions within a strictly defined region [310, 753].

The surface modeling is connected with the basic concepts, introduced by Tasker [755] in a discussion of the stability of surfaces of ionic or partly ionic crystals. According to classical electrostatic criteria, the stability of a compound surface depends on the characteristics of the charge distribution in the structural unit that repeats itself in the direction perpendicular to the surface. The surface can be studied by considering the crystal as a stack of atomic planes. Each plane consists of sublattices of nonequivalent atoms; a sum over each sublattice on each plane gives the total electrostatic potential. For perpendicular distances z greater than a few interionic spacings, the contribution from a planar sublattice reduces to the particularly simple form

$$V(z) = \frac{2\pi}{S} qz \quad (11.6)$$

where S is the area of the unit cell in the plane and q is the planar sublattice charge. This expression is identical to the potential due to an infinite charged plane of charge density $\rho = \frac{q}{S}$; the field $E = \frac{2\pi}{S} q$ due to the charged plane is constant. Since $V(z)$ and E do not diminish with increasing distance z , the electrostatic sum must be over the whole crystal as stacks of planes unless cancelation of these terms occurs. Although the potential $V(z)$ becomes infinite at infinite distances from the plane, it should be noted that when the crystal is constructed as a neutral block, the infinities cancel and the potential becomes constant at large distances. In fact, it becomes zero in all cases except where there is a dipole moment perpendicular to the surface. Similarly the field E cancels to zero outside a neutral crystal block, irrespective of the stacking sequence.

The repeat unit of a stack of planes is introduced when analyzing the distribution of the bulk structure atoms over the atomic planes in the direction z normal to the surface. This distribution depends on the oxide bulk structure and Miller index,

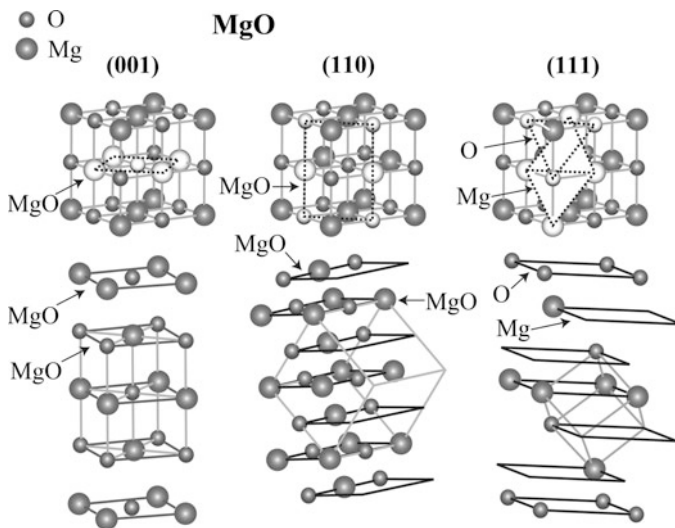


Fig. 11.2 Stacking of atomic planes for MgO surfaces

defining the surface. The three different possible stacking sequences define three types of surfaces.

As a simplest case of the *type 1 surface*, we consider the (001) surface of MgO crystal (Fig. 11.2).

The neutral bulk unit cell consists of two atoms (Mg and O), and both of them occupy the same atomic plane. Each atomic plane has overall zero charge since it consists of both anions and cations in stoichiometric ratio. The potential $V(z)$ cancels on each plane since the contributions of the sublattices are equal and opposite. Additional planes in the stacking sequences make no contribution to the energy of ions in the bulk of crystal, and the lattice sums required for the Madelung energy at any ion site need to include only a few planes either side of that site. It is seen from Fig. 11.2 that the (110) surface of MgO crystal refers also to type 1.

When a stacking sequence consists of charged planes, there are two possible cases. In the first case, the repeat unit has no dipolar moment perpendicular to the surface (*type 2 surface*); in the second case, the stack of charged planes has a nonzero dipole moment along the z -direction (*type 3 surface*).

For the type 2 surface, each plane contributes a term in the potential $V(z)$, but a sum over the planes in repeat units cancels the potential to zero. Addition of extra neutral repeat units at the type 2 surface of the crystal cannot therefore affect the energy of ions in the bulk, and again the Madelung sums for the potential at any ion site are rapidly convergent. The (110) surface of the TiO_2 rutile structure (Fig. 11.3) is an example of a type 2 surface.

Indeed, the bulk-crystal unit Ti_2O_4 atoms are distributed over three planes with the surface unit cells consisting of one oxygen atom (two planes) or Ti_2O_2 units (one plane). The atomic planes in this repeating unit are charged ($q = -2$ for oxygen

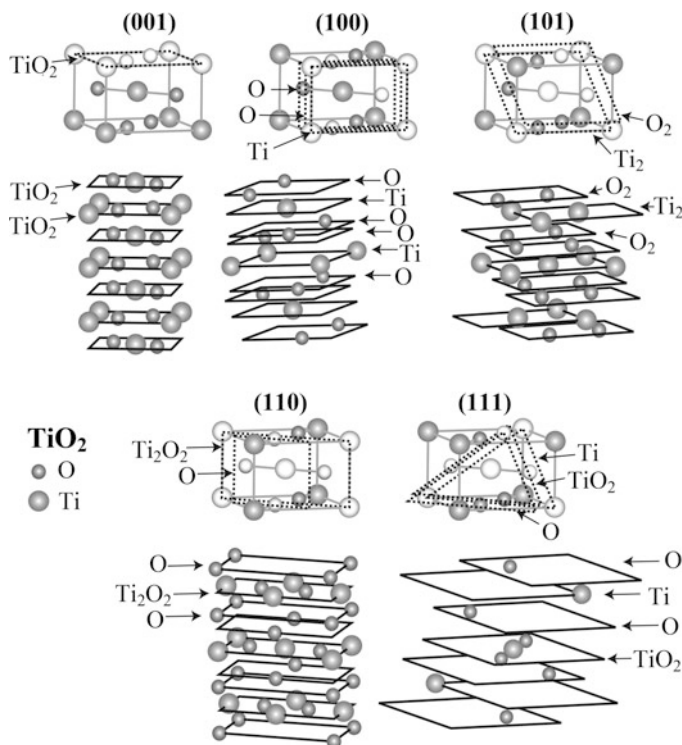


Fig. 11.3 Stacking of atomic planes for rutile TiO_2 surfaces

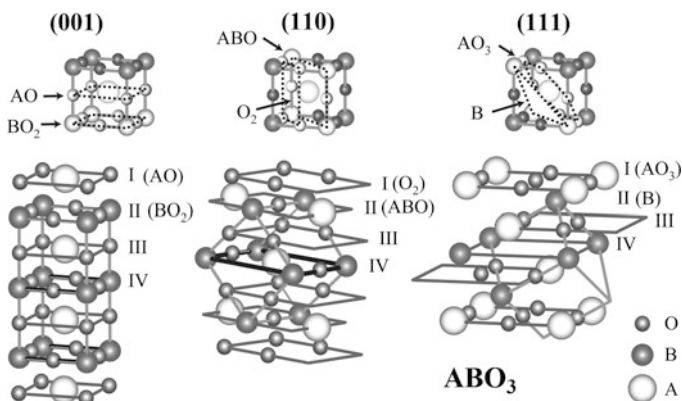
planes and $q = +4$ for Ti_2O_2 planes). However, the stacking of planes with the repeat unit as $\text{O}-\text{Ti}_2\text{O}_2-\text{O}$ allows one to obtain zero as its dipole moment along the z -direction. Two other terminations ($\text{O}-\text{O}-\text{Ti}_2\text{O}_2$ and $\text{Ti}_2\text{O}_2-\text{O}-\text{O}$) give the repeat unit that bears a nonzero dipole moment. This example demonstrates that the surface orientation only is not always sufficient to refer the surface to the one of three types, especially when various terminations may be produced. The atomic TiO_2 planes in the repeat unit of the (001) surface of rutile (Fig. 11.3) are also charged ($q = -2$), but the dipole moment of any stack of an integer number of such planes is again zero (type 2 surface). The repeat units for (100) and (101) type 2 surfaces have also zero dipole moment (O - and O_2 -terminated repeat units of 6 and 3 atomic planes, respectively, can be chosen).

For the majority of cases of the oxide surfaces, the stacking sequence of charged planes has a dipole moment perpendicular to the surface. In particular, the stacks of alternately charged planes form the repeat unit for (111) surface of MgO (Fig. 11.2) and (101) surface of TiO_2 (Fig. 11.3).

Table 11.3 gives the formal plane charges in the stack of different surfaces in the cubic perovskite ABO_3 crystal with one formula unit in the primitive unit cell. The bulk atom distribution over atomic planes is shown on Fig. 11.4.

Table 11.3 Formal and calculated (in brackets) atomic plane charges of ABO_3 cubic perovskite

Surface Termination	(001)		(110)		(111)	
	AO	BO ₂	ABO	O ₂	AO ₃	B
$A^I B^V O_3$ (KNbO ₃)	-1	+1	+4	-4	-5	+5
$A^{II} B^{IV} O_3$ (SrTiO ₃)	0(+0.27)	0(-0.27)	+4	-4	-4	+4
$A^{III} B^{III} O_3$ (LaMnO ₃)	+1(+0.95)	-1(-0.95)	+4	-4	-3	+3

**Fig. 11.4** Stacking of atomic planes for cubic perovskite ABO_3 surfaces

All the surfaces in cubic perovskite structure are type 3 surfaces being stacks of alternately charged planes. It is less obvious in the case of the (001) surface in $A^{II}B^{IV}O_3$ as the repeat unit consists of neutral atomic planes (see below). It is also seen that the charge of the atomic plane depends both on the oxidation states of A and B atoms (the sum of oxidation states is in all cases 6) and Miller indexes of the surface.

For the stacking sequence of alternately charged planes (producing a dipole moment perpendicular to the surface), the two-plane repeat unit produces a potential at large distances whose magnitude is given by

$$V = 2\pi|q|\frac{a}{S} \quad (11.7)$$

where a is the interplanar spacing. Addition of an extra neutral repeat unit of two planes on the surface of the crystal will affect the energy of ions, an infinite distance below the surface. Consequently, the Madelung sum cannot be truncated and must include contributions from every plane out to the surface. The potential at any ion site never reaches a constant bulk value, the energy of a neutral pair of ions never reaches the usual cohesion energy, and the surface energy is infinite [755]. The stacking of planes for rutile (100), (101), and (111) type 3 surfaces is more

complicated as it cannot be named as the stacking sequence of alternatively charged planes.

The classification of the surfaces by Tasker is based on the formal ionicities (oxidation states) of metal atoms. As we already noted, the oxidation state and calculated atomic charges are close only in purely ionic compounds (e.g., MgO). As we have seen in Chap. 9, the transition-metal atom charges differ essentially from the oxidation states due to the covalence part of the chemical bonding with oxygen atom.

In Table 11.3 are given in brackets the atomic plane charges for (001) surface in SrTiO_3 and LaMnO_3 crystals calculated for the bulk crystals with the use of Wannier-type atomic functions in the population analysis, see Chap. 9 and reference [719]. As the Ti–O bond in SrTiO_3 presents a non-negligible part of covalent character, the actual charges of atomic planes SrO and TiO_2 are nonzero. This means that SrTiO_3 (001) should be considered as a polar (type 3) surface.

Type 1 or 2 surfaces have a zero dipole moment in their repeat unit and are thus potentially stable. By contrast, polar type 3 surfaces have a diverging electrostatic surface energy due to the presence of a nonzero dipole moment not only on the outer layers but also on all the repeat units throughout the material, [751]. An electrostatic instability of type 3 surfaces results from the presence of that macroscopic dipole. Type 3 surfaces can be stabilized when the macroscopic field is removed by surface reconstruction, absorption of charged specks, and so on. The modification of the surface electronic structure due to the reconstruction introduces compensating charges in the outer planes, stabilizing the surface structure. The absorption of charged specks is also a very effective mechanism to achieve the stabilization of polar orientations. Indeed, polar orientations are generally much more reactive than cleavage planes [751].

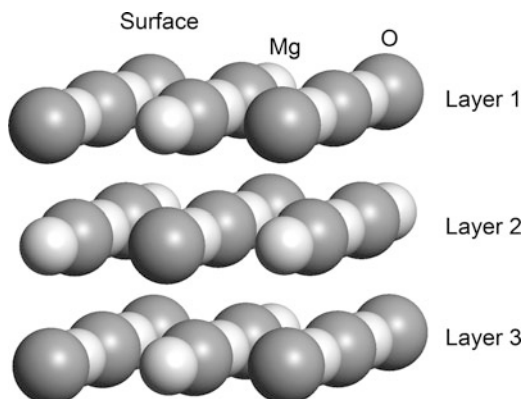
The classification of surfaces considered above was introduced for ionic or semi-ionic metal oxides. In covalent solids, the creation of a surface requires cutting covalent bonds, which means that dangling bonds would be present at the surface. The saturation of dangling bonds by chemisorption is important, for example, in silicates. When a surface is cut out from the bulk, unstable Si–O radicals at the surface react readily with water to give a fully hydroxylated surface with hydrophilic character [552].

Tasker's classification of surfaces allows some qualitative conclusions to be made about the surface stability. The quantitative calculations of the surface formation energy in slab models are considered in the next sections.

11.1.3 *Single- and Periodic-Slab Models of MgO and TiO_2 Surfaces*

As was seen above in the slab model, the surface plane is supposed to be fixed by its orientation (by the set of Miller indices) relative to the bulk structure and

Fig. 11.5 3-layer (3-plane) slab for MgO (001) surface



its symmetry elements. All the atoms of the bulk primitive unit cell are distributed within one or several atomic planes with the same 2D-translation periodicity, see Figs. 11.2–11.4. Let these planes of atoms form a layer, being stoichiometric and neutral as by definition it contains all the atoms of the bulk primitive unit cell. Depending on the host-crystal structure, the one-layer single slab can have zero (type 1 and type 2 surfaces) or nonzero (type 3 surfaces) dipole moment along the normal to the surface plane. To ensure the zero dipole moment in the type 3 surface modeling, the nonstoichiometric slabs can be used.

Figure 11.3 shows that for the type 3 (111) surface of rutile TiO_2 structure, O- or TiO_2 -terminated layer of the smallest thickness consists of 5 atomic planes: O–Ti–O– TiO_2 –O or TiO_2 –O–Ti–O– TiO_2 , respectively.

For the cubic perovskite ABO_3 (001) surface, the nonstoichiometric slabs with AO or BO_2 terminations can be introduced. Figure 11.4 shows a AO-terminated slab, consisting of 7 atomic planes—4 AO planes and 3 BO_2 planes. As is seen from Fig. 11.4, the slab termination is different for different surfaces.

The symmetry of the single slab corresponds to one of 80 diperiodic (layer) space groups. Figure 11.5 shows a 3-layer single-slab model of (001) surface of MgO crystal (each layer consists of one atomic plane). The symmetry group of this slab DG61 ($P4/mmm$) belongs to a square system.

Figure 11.6 shows a 3-layer single slab of (110) rutile TiO_2 . In this case, each layer consists of 3 atomic planes. In particular, the upper layer includes an oxygen plane (O1 atoms), a Ti_2O_2 plane (Ti1, Ti2, O2, O3 atoms), and an oxygen plane (O4 atoms). Oxygen atoms O5 belong to the next O– Ti_2O_2 –O layer. The symmetry group of this slab is DG37 ($Pmmm$).

In the multislab model (periodically repeated slab), the 3D periodicity is restored: slab of n layers (nL -slab) is supposed to be periodically repeated along the normal to the surface (let the translation vector of a single slab be $\mathbf{c}$). Figures 11.7 and 11.8 show the periodic 3-layer slabs, modeling MgO (001) and TiO_2 (110) surfaces, respectively.

Fig. 11.6 3-layer (9-plane) slab for rutile TiO_2 (110) surface

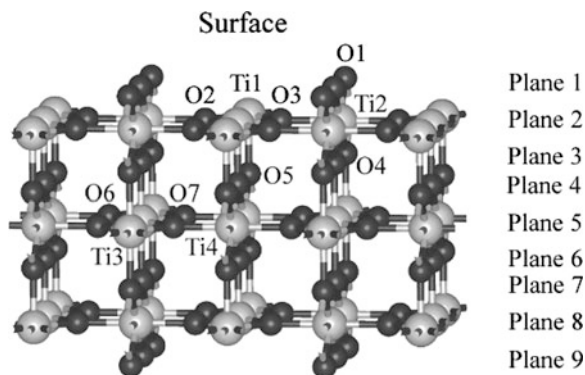
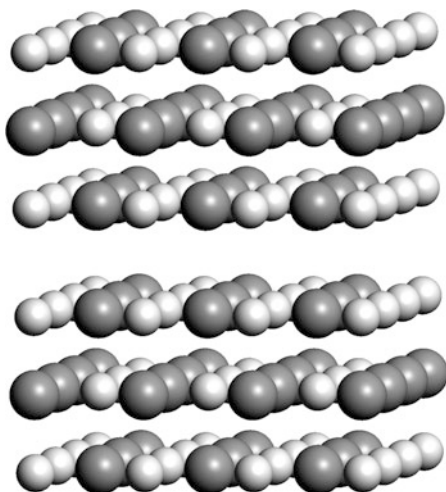


Fig. 11.7 Periodic-slab model of (001) MgO surface



The corresponding space-symmetry groups can be found from Table 11.1: $G123(D_{4h}^1)$ and $G47(D_{2h}^1)$, for MgO and TiO_2 3-layer slabs, respectively.

In 3D-slab calculations the results depend not only on the number of layers in the slab (slab thickness) but also on the separation between periodically repeated slabs defined both by the slab thickness and the length of the translation vector along the normal to the surface. The interslab distance (vacuum gap) is equal to the difference between the length of translation vector c and the vertical distance between the top atoms of one slab and the nearest repeated one, *that is*, the difference between the translation vector c and the single-slab thickness (see Figs. 11.7 and 11.8).

The symmetry of the 3D-slab model is given by one of the 3D space groups G (see Table 11.1) and may depend on the slab thickness, *that is*, number of layers in the slab and its termination. As is seen from Fig. 11.1, for MgO crystal (001) surface, slabs of an odd number of atomic planes have inversion symmetry (relative to the central atomic plane), but slabs of an even number of atomic planes have no inversion symmetry. For the cubic perovskite ABO_3 (001) surface, the

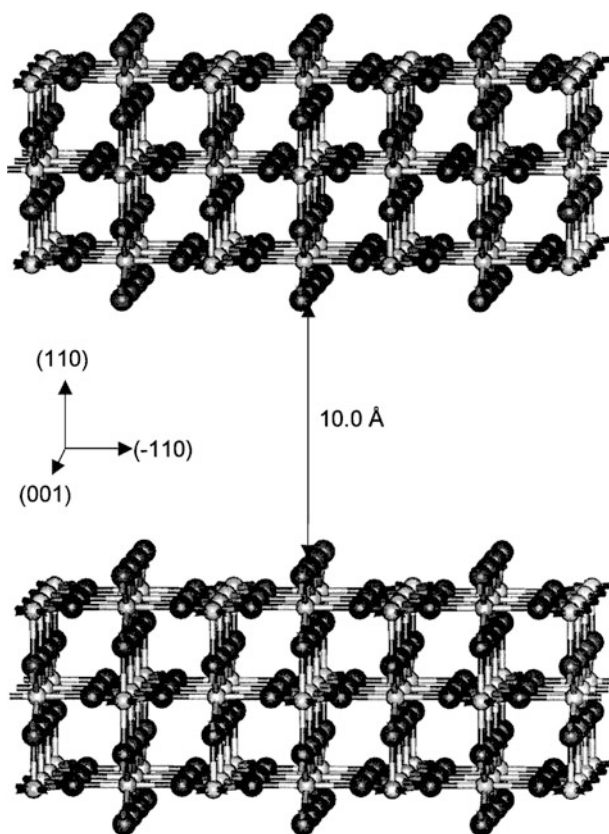


Fig. 11.8 Periodic-slab model of rutile TiO_2 (110) surface

stoichiometric slabs ($\text{AO-BO}_2\text{-AO-BO}_2\text{-}$) consist of an even number of atomic planes and have no inversion symmetry. But the nonstoichiometric AO- or $\text{BO}_2\text{-}$ terminated slabs have inversion symmetry relative to the central AO or BO_2 planes, respectively.

Note that the space-symmetry group of a periodic slab differs from the space group of the host crystal. As an example, we consider MgO crystal with symmetry of space group O_h^5 . The single-slab model refers to a square lattice and has the symmetry of DG 61 ($P4/mmm$) or DG 51 ($P4mm$) for slabs of odd and even number of planes, respectively (see Figs. 11.2 and 11.5). As is seen from Table 11.1, the periodic-slab model in these cases has the symmetry of D_{4h}^1 (G123) or C_{4v}^1 (G99) space groups, respectively.

One of the goals of slab-model studies is to investigate the dependence of the calculated surface energy on the dimensionality of the slab model and on the Hamiltonian applied. The surface energy E_s^n per unit of surface area for an n -layer slab is defined by the relation

$$E_s^n = \lim_{n, W \rightarrow \infty} \frac{1}{2S} [E(n, W) - nE_b] \quad (11.8)$$

where $E(n, W)$ is the total energy in a 3D-slab calculation of an n -layer slab with the vacuum gap W and E_b is the total energy of primitive unit cell in a separate bulk calculation. In the 2D-slab model, W is infinite, *that is*, $E(n, \infty)$ is the n -layer single-slab energy $E(n)$. In (11.8), S is the surface area per repeating 2D-unit cell; the factor $1/2$ accounts for the existence of two limiting surfaces. E_s^n is the energy per unit area required to form the surface from the bulk, and it is intrinsically a positive quantity.

The value of surface energy is very dependent not only on $E(n, W)$ but also on the bulk total energy E_b used in (11.8). In (11.8), total energies from 3D ($E(n, W)$) or 2D ($E(n, \infty)$) systems are used, creating a problem of equivalent accuracy in periodic codes for 3D and 2D systems. Boettger pointed out [756] that any difference between E_b and the change in $E(n, w)$ with slab thickness will cause the calculated surface energy to diverge linearly with n . Thus, increasing the slab thickness must sooner or later lead to unacceptable results because the bulk energy from a separate calculation will never exactly equal the slope of the slab energy versus n , [757]. To avoid the divergence problem, it was suggested [756], for each slab thickness n , pick as the bulk energy E_b the differential increase in the slab total energy upon addition of one layer of material:

$$E_s^n = \lim_{n, W \rightarrow \infty} \frac{1}{2S} [E(n, W) - n(E(n, W) - E(n-1, W))] \quad (11.9)$$

In this expression, E_b has been replaced by $(E(n, W) - E(n-1, W))$. This relation has the merit of using only slab-related quantities, making no reference to separately calculated bulk energies.

The surface formation-energy calculations impose two strong requirements to the accuracy of calculated energies: (1) numerical precision and (2) computational consistency. While the first condition may be relatively easily satisfied by increasing the computational thresholds, the second one can lead to considerable problems due to inevitable approximations that are inherent to all quantum-mechanical computation techniques [663]. The surface modeling of real interest lies in a semi-infinite crystal, *that is*, the calculation of the surface-energy limit when n and W tend to infinity. However, one could not a priori guarantee the convergence to definite limit in (11.8). So, the existence of such a limit is the obligatory condition for the possibility to obtain the correct value of E_s using slab models.

Use of different surface models (2D and 3D slabs) and basis sets in HF (LCAO) and DFT (PW) calculations makes it difficult to understand the origin of differences in calculated results that may be due both to the model applied and to the features of the calculation scheme chosen (basis set, integral approximations, Brillouin-zone sampling, and so on).

The first attempt to compare 2D- and 3D-slab models within the same calculation scheme was made in [758] for HF LCAO studies of the surface properties of BaTiO_3

Table 11.4 Convergence of results for the MgO (001) single slabs depending on the 2D slab thickness (E_s —surface energy in J/m², E_F —Fermi energy in H),[759]

Number of layers, n	HF		DFT (default ABS)		DFT (extra ABS)	
	E_s	E_F	E_s	E_F	E_s	E_F
1	1.4571	−0.3293	1.5516	−0.1035	1.5506	−0.1075
2	1.4689	−0.3397	1.5766	−0.1082	1.5344	−0.1226
3	1.4678	−0.3403	1.5341	−0.1217	1.5335	−0.1217
4	1.4678	−0.3407	1.5630	−0.1140	1.5339	−0.1208
5	1.4678	−0.3409	1.5341	−0.1204	1.5336	−0.1203
6	1.4678	−0.3410	1.5554	−0.1157	1.5337	−0.1199
9	1.4678	−0.3413	1.5342	−0.1193	1.5337	−0.1193
12	1.4678	−0.3414	1.5460	−0.1171	1.5338	−0.1190
15	1.4678	−0.3415	1.5345	−0.1188	1.5338	−0.1189
20	1.4678	−0.3415	1.5417	−0.1175	1.5338	−0.1187

in the cubic perovskite structure. The authors of [758] concluded that results for periodic 3D slabs are systematically affected by the interactions among repeated images and possibly the fictitious field imposed by periodic boundary conditions.

In the LCAO approximation (for HF, KS, and hybrid HF–DFT Hamiltonians), the systems periodic in 2 (2D slabs) and 3 dimensions (3D crystals) can be treated on an equal footing. The LCAO package CRYSTAL [21] gives the unique possibility to compare results of 2D- and 3D-slab models when the LCAO basis set is used. Such a comparison was made in [759] for the (001) surface of MgO crystal and in [760] for the (110) surface of rutile TiO₂.

We discuss here the results for MgO crystal. In [759], the experimental value 4.21 Å of the *fcc* lattice constant for the bulk crystal was adopted in slab calculations. As was already noted, the square unit cell of one layer is stoichiometric as it consists of one Mg and one O atoms lying in one (001) plane (see Fig. 11.5). The calculations were made for single slabs of one to twenty atomic layers in a truncated-bulk geometry without relaxing the positions of atoms. The converged surface-energy value was obtained for the single slab of 5 layers. The dependence of 3D-slab calculation results on the vacuum gap was investigated via calculating the 5-layer 3D slabs with gaps up to 42 Å. The symmetry of slabs depends both on the 2D or 3D periodicity and on the evenness of the number n of atomic layers. For 3D slabs, the tetragonal space groups G 123 (*P4/mmm*) and G 99 (*P4mm*) with tetragonal lattice constant $a' = a/2 = 2.977$ Å were used for odd and even n , respectively. The translation vector $\mathbf{c}$ was varied in the calculations.

Table 11.4 shows the convergence of results for the single-slab (2D) MgO (001) surface model depending on the slab thickness.

To eliminate the results dependent on Brillouin-zone sampling, the dense Monkhorst–Pack $\mathbf{k}$ -point mesh was used. For primitive unit cells, the $12 \times 12 \times 12$ and 12×12 special-point sets have been taken for bulk and slab calculations, respectively. In the case of 3D slabs, the number of points in the third $\mathbf{k}$ -direction depends on the chosen value of the $\mathbf{c}$ translation vector in direct space. The latter was

chosen to provide a similar size in all directions of the corresponding cyclic model of the crystal (the crystal is composed of equidistant supercells). The increase of the unit cell in direct space for producing the 2D supercell was accompanied by the corresponding reduction in the k -point mesh in the reciprocal space. The same all-electron basis sets have been used both in HF and DFT calculations to allow the direct comparison of obtained energies. The choice of high precision tolerances for the Gaussian overlap criteria in truncation of Coulomb and exchange series ensured the high numerical accuracy required for the evaluation of the corresponding surface energy. In DFT calculations the exchange and correlation were treated in PWGGA approximation. In the CRYSTAL code the periodic DFT version in a basis of local Gaussian-type functions is implemented to avoid the numerical integration. This auxiliary basis set (ABS) is used for fitting the exchange-correlation potential. In DFT computations two types of ABS were used: (1) ABS1—even tempered basis set of 12 s -type Gaussian-type functions and (2) the basis proposed with extra p -, d -, f -, and g -functions ABS2.

Table 11.4 shows the fast convergence of 2D periodic results for surface energy with increasing number of layers. Three to five MgO layers are sufficient to obtain the converged values of the HF surface energy for unrelaxed slabs, in agreement with the results of other calculations, [761]. The convergence of the Fermi-level energy (highest-occupied one-electron energy level for the slab) is much slower. The limiting value seems to be reached just at $n = 20$. As seen from Table 11.4, the use of extended ABS2 (for the fitting of the exchange-correlation potential) proved to be necessary for obtaining the convergence of the surface energies. The DFT values of surface energy exhibit a similar fast convergence with the slab thickness as HF values, and the difference between HF and DFT surface energy does not exceed 5%. However, the initial part of E_s^n for $n = 3$ has a different sign of slope for these two methods. The DFT result, which corresponds to the decrease of E_s^n with n , seems to be more physically reliable. There is no large discrepancy between HF and DFT atomic charges, although the latter exhibit a slightly more covalent character [759].

The numerical value of Fermi energy E_F may be used for approximate estimation (according to the Koopmans' theorem) of the surface ionization potential that defines the adsorption energies. Due to the correlation effects, the DFT Fermi energy E_F differs essentially from that in HF calculations. Table 11.4 shows that E_F is inside the valence band of a perfect crystal, *that is*, the resonance surface states are predicted both in HF and DFT single-slab calculations.

Taking into account the convergence of results obtained for 2D slabs, only the 5-layer 3D models have been calculated in [759]. The results are given in Table 11.5. Table 11.5 shows that the 3D slab with vacuum gap 6–8 Å gives the converged (001) surface energy of ionic MgO crystal. The DFT values of E_s^n exhibit a similar fast convergence as HF ones, and the difference between them is small. The convergence of the surface energy with the single-slab thickness is slower for rutile TiO₂ due to the partly covalent Ti–O interaction. Table 11.6 demonstrates the convergence of the surface energy in all-electron HF LCAO single-slab calculations [760] of the (110) surface of rutile TiO₂.

Table 11.5 Convergence of the results for the periodically repeated 3D MgO (001) unrelaxed slab depending on the vacuum gap for 5-layer models (primitive 2D cell)[759] (E_s —surface energy in J/m², E_F —Fermi energy in a.u.)

Cell dimensions, Å		k-point set	HF		DFT	
Gap	c		E_s	E_F	E_s	E_F
∞	∞	12 12	1.468	−0.3409	1.532	−0.1202
2.105	10.525	12 12 4	5.365	−0.2458	4.8937	−0.0486
4.210	12.630	12 12 3	1.503	−0.3181	1.555	−0.1164
6.315	14.735	12 12 3	1.468	−0.3215	1.533	−0.1170
8.420	16.840	12 12 2	1.468	−0.3239	1.533	−0.1174
12.630	21.050	12 12 2	1.468	−0.3273	1.533	−0.1180
21.050	29.470	12 12 1	1.468	−0.3312	1.533	−0.1186
42.100	50.520	12 12 1	1.468	−0.3352	1.532	−0.1193

Table 11.6 Convergence of the results for single-slab (2D) model of (110) rutile TiO₂ surface[760] (E_s —surface energy, E_F —Fermi energy)

No. of atomic planes (layers)	No. of Ti planes	Total energy (a.u.)	E_s (J/m ²)	E_F (a.u.)
Perfect crystal	—	−1996.8016	—	−0.3077
9	3	−5990.211	2.193	−0.4171
15	5	−9983.815	2.183	−0.4235
21	7	−13977.418	2.183	−0.4237
27	9	−17971.021	2.183	−0.4237

It follows from Table 11.6 that surface energy is sufficiently well reproduced for the 5-layer (15 atomic planes) slab, in accordance with the results of HF all-electron calculations [762]).

As in the case of MgO crystal, the convergence of the Fermi energy with slab thickness is much slower than that of surface energy (see the last column of Table 11.6). Calculations of 3D slabs for rutile TiO₂ [760] show that the periodic supercells in the plane with extensions $2c \times 2a\sqrt{2}$ and $2c \times a\sqrt{2}$ give the same surface energies for the vacuum gap values 41 Å and 15 Å, respectively.

The LCAO approximation allows comparison of the electron-charge distribution in the bulk crystal and on the surface. The application of Wannier functions for this comparison can be found in [764], where the Boys localization criteria were applied and only the valence-band states were included for WFs generation (for bulk crystals, such an approach is discussed in Chap. 9). As was seen in Chap. 9 for bulk crystals, the population analysis using Wannier-type atomic orbitals (WTAO) gives more adequate results for charge distribution than traditional Mulliken population analysis or the projection techniques applied in PW calculations.

The WTAOs for systems with 2D periodicity were generated in [763] for the first time and used for the surface-charge distribution analysis in a single-slab model of (001) MgO and (110) TiO₂. First, WFs of the bulk crystal, corresponding to valence bands, were used as a tool allowing one to estimate the values for the slab

parameters needed to adequately model the surface electronic structure. Secondly, a minimal valence basis of WTAOs, which are the Wannier functions, generated from occupied and vacant Bloch states and centered on atoms, was used for the analysis of chemical bonding at the surfaces under study. HF LCAO calculations were performed for 3-layer single slabs of (001) MgO (3 atomic planes) and rutile (110) TiO₂ (9 atomic planes), see Figs. 11.5 and 11.6.

For construction of the WTAOs for the minimal valence basis, the corresponding energy bands are to be chosen. The *s*- and *p*-bands of oxygen atoms form the higher valence bands in both slabs considered. In the case of the TiO₂ slab, the *d*-bands of the titanium atoms are the lower conduction bands, while the *s*-bands of the metal atoms in both slabs are located among vacant states high in energy. The latter makes the contribution of *s*-WTAOs of the metal atoms into the covalence of these atoms negligible.

One can estimate the slab thickness needed for surface modeling by a preliminary qualitative analysis of the behavior of WFs, corresponding to valence bands of a bulk crystal. Indeed, the off-diagonal elements of the density matrix of a bulk crystal fall off with distance as the Wannier functions of valence bands or faster (exponentially in the case of insulators), see Chap. 4. Thus, beyond a sufficiently large domain of the crystal (basic domain), the values of Wannier functions, assigned to the central unit cell of the domain, are negligible. Consequently, truncation of the rest of the crystal and imposition of the periodical boundary conditions on the domain-edge atoms practically do not affect the electron-density distribution inside the domain chosen. The basic domain of the crystal corresponds to a special set of *k*-points, which provides a convergence of the calculation results relative to the extension of this set.

A similar ideology can be used for the slab model. Let us consider the slab as consisting of the finite number of atomic planes. Let, at the surface planes of the slab chosen, the numerical values of bulk valence-band WFs be close to zero. The corresponding number of atomic planes determines the minimal thickness of a slab for the studied surface, which can be expected to provide the convergence of the results relative to increasing its thickness. However, the convergence might not occur for the chosen thickness of the slab due to an absence of periodical boundary conditions at the slab surface. But, if the slab WFs, localized in its central part, are close to the bulk ones and the localization of the slab WFs, centered near the slab edge, is to a certain extent the same as in the bulk crystal, the electron density in the middle part of the slab does not differ much from the bulk electron density and would not change when the thickness of the slab is increased. Thus, the analysis of bulk WFs can help in estimating the slab thickness, which allows the bulk-like results in the central planes of the slab to be obtained and thus corresponds to more or less adequate surface modeling. Still, this is only a qualitative and estimative analysis.

Let us illustrate the aforesaid by the results obtained for MgO and TiO₂ crystals. In [763], it is shown that Wannier functions for the valence bands of the bulk MgO crystal calculated along the [001] direction are practically completely localized inside a domain containing just three (001) atomic planes. Furthermore, according

Table 11.7 Atomic charges for the single MgO 3-plane (001) surface and TiO₂ 9-plane (110) surface slabs and bulk crystals,[763], (NWTAO is nonorthogonal WTAO, OWTAO is orthogonal WTAO)

A) MgO crystal					
		Atomic charges, e			
	Atoms	NWTAOs	OWTAOs	Mulliken	Löwdin
	O1, Surface	−1.98	−1.96	−1.96	−1.83
	Mg1, Surface	2.00	1.97	1.96	1.83
	O2	−1.99	−1.96	−1.97	−1.82
	Mg2	1.97	1.95	1.97	1.82
	O Bulk	2.00	−1.98	−1.98	−1.82

B) TiO ₂ crystal					
		Atomic charges, e			
Planes	Atoms	NWTAOs	OWTAOs	Mulliken	Löwdin
1	O1, surface	−1.33	−1.30	−1.13	−0.88
2	Ti1, surface	2.99	2.87	2.62	1.84
	Ti2	2.86	2.79	2.54	1.63
	O2,3, surface	−1.48	−1.44	−1.35	−0.86
3	O4	−1.57	−1.51	−1.38	−0.91
4	O5	−1.54	−1.45	−1.28	−0.82
5	Ti3	3.06	2.95	2.66	1.72
	Ti4	3.01	2.93	2.65	1.73
	O6,7	−1.50	−1.46	−1.33	−0.87
Bulk	Ti	2.76	2.70	2.66	1.72
	O	−1.38	−1.35	−1.33	−0.86

to calculations, the difference between these WFs and the WFs generated for the slab and centered on the plane 2 (see Fig. 11.5) is negligible. This means that the 3-plane slab is sufficient for modeling the (001) surface properties of MgO. As we demonstrated above, this consideration is, in principal, confirmed by thorough calculations of MgO slabs with a varied thickness—the surface energy and other characteristics converge at the 3-plane slab.

In the case of TiO₂, the bulk WFs does not fit into the 9 atomic planes shown in Fig. 11.6. As a result, the WFs, calculated from the slab states and localized in the “central” region of the slab, are different from the corresponding bulk WFs. Consequently, 9 planes are not sufficient for correct modeling of the TiO₂ crystalline surface. This result correlates with the results given in Table 11.6.

As seen from Table 11.7A, the values of atomic charges for the MgO slab correspond to the purely ionic type of chemical bonding both at the surface and inside the slab. The charges in the slab model practically coincide with the bulk ones. The results, obtained by the WTAOs method and according to the traditional Mulliken and Löwdin schemes, are nearly the same.

For the TiO₂ slab, the Mulliken and Löwdin population analyses give contradictory results. Particularly, as noted in Table 11.7B, the values of atomic charges at the

surface planes of the slab, calculated according to the Mulliken scheme, are smaller in magnitude than those inside the slab. This corresponds to a lower ionicity at the crystalline surface compared to the bulk. An opposite tendency is demonstrated in the Löwdin analysis, where the surface charges are larger or the same as in the bulk. Besides, the absolute values of the charges obtained according to the two traditional schemes are quite different from each other. Table 11.7B shows that the analysis performed by the orthogonal and nonorthogonal WTAOs gives approximately the same results. They show the tendency of decreasing the ionicity level at the surface, which is similar to the results of the traditional Mulliken analysis.

Let us consider the values of atomic charges, obtained for the central planes of the slab (planes 3–7 on Fig. 11.6). Due to the symmetry of the slab, the planes 6 and 7 are equivalent to the planes 4 and 3, respectively. As noted above, a nine-plane slab is not sufficient to model the TiO_2 surface, as the electron density at the central planes of the slab is different from that of the bulk crystal. However, the values of atomic charges calculated according to both the Mulliken and Löwdin schemes practically coincide with the bulk ones (Table 11.7B). In contrast to these results, the population analysis based on WTAOs reproduces this slab–bulk misfit: the values for the charges of atoms of the inner planes in the slab and the bulk crystal differ noticeably.

When analyzing the Ti–O bond orders, which are given in Table 11.8, one can conclude the following.

The values, obtained by the two traditional schemes, can be hardly interpreted. Some of the bonds have the same orders in both schemes (Ti1–O5, Ti2–O1, Ti3–O4, Ti4–O5), while the others are essentially different (Ti1–O2, Ti2–O2, Ti3–O6, Ti4–O6), see Fig. 11.6. As to the results obtained by orthogonal and nonorthogonal WTAOs, they are close for all the bonds under consideration.

Every oxygen atom (excluding the atoms O1) has two neighboring titanium atoms at a distance of 3.687 a.u. and one at 3.727 a.u. (three-coordinated atoms). The O1 atoms are two-coordinated and have the neighbors only at 3.687 a.u. The titanium atoms are six-coordinated (Ti2, Ti3, Ti4) or five-coordinated (Ti1) and have four neighboring oxygen atoms at 3.687 a.u. and two or one at 3.727 a.u., respectively. Only for some of the atoms (Ti2, O2, Ti4) do the Mulliken and Löwdin schemes allow the larger orders for the shorter bonds (among the nearest-neighbor Ti–O bonds) to be obtained. For other atoms, the values of the shorter bond orders are approximately of the same magnitude as the longer ones (O6) or even significantly smaller (Ti3, O4, O5), which is unreal from the chemical point of view. The WTAO method for all the atoms gives the expected tendency—the shorter is a bond, the larger is the value of the corresponding bond order. Also, WTAO analysis gives the noticeably larger values for the in-surface bonds. This agrees with the decreased values of the atomic charges at the surface relative to those at the inner part of the slab.

The results of the calculations of atomic covalences are presented in Table 11.9. Again, the Mulliken and Löwdin methods demonstrate contradictory and obscure bulk–surface tendencies. For some atoms the values of the covalences, calculated according to the Mulliken scheme, are close to the Löwdin ones, and for the other,

Table 11.8 Orders of the bonds between the near-neighbor Ti and O atoms in the single TiO₂ nine-plane (110) surface slab and bulk crystal (NWTAO is nonorthogonal WTAO, OWTAO is orthogonal WTAO, *d* is a distance between neighbor atoms, s denotes in-surface atom) [763]

Atom	Neighbor atoms			Bond orders			
	Atom	<i>N</i>	<i>d</i>	NWTAO	OWTAO	Mulliken	Löwdin
O1	Ti2, s	2	3.687	0.54	0.55	0.80	0.79
Ti1	O2,3, s	4	3.687	0.37	0.39	0.42	0.62
	O5	1	3.727	0.17	0.25	0.62	0.63
Ti2	O1, s	2	3.687	0.54	0.55	0.80	0.79
	O4	2	3.687	0.27	0.29	0.47	0.50
	O2,3	2	3.727	0.11	0.13	0.17	0.40
O2,3	Ti1, s	2	3.687	0.37	0.39	0.42	0.62
	Ti2	1	3.727	0.11	0.13	0.17	0.40
O4	Ti2	2	3.687	0.27	0.29	0.47	0.50
	Ti3	1	3.727	0.17	0.21	0.52	0.54
O5	Ti4	2	3.687	0.30	0.32	0.52	0.54
	Ti1	1	3.727	0.17	0.25	0.62	0.63
Ti3	O6,7	4	3.687	0.31	0.32	0.34	0.54
	O4	2	3.727	0.17	0.21	0.52	0.54
Ti4	O5	4	3.687	0.30	0.32	0.52	0.54
	O6,7	2	3.727	0.22	0.23	0.34	0.53
O6,7	Ti3	2	3.687	0.31	0.32	0.34	0.54
	Ti4	1	3.727	0.22	0.23	0.34	0.53

Table 11.9 Atomic covalences for the single TiO₂ nine-plane (110) surface slab and bulk crystal [763], (NWTAO is nonorthogonal WTAO, OWTAO is orthogonal WTAO)

Planes	Atoms	Atomic covalences			
		NWTAOs	OWTAOs	Mulliken	Löwdin
1	O1, surface	1.20	1.24	1.86	1.88
2	Ti1, surface	1.74	1.91	2.44	3.35
	Ti2	1.92	2.03	2.36	3.02
	O2,3, surface	0.95	1.02	1.28	2.01
3	O4	0.80	0.90	1.76	1.95
4	O5	0.85	0.99	1.92	2.07
5	Ti3	1.64	1.82	2.49	3.47
	Ti4	1.73	1.85	2.87	3.45
	O6,7	0.92	0.99	1.27	2.03
Bulk	Ti	2.06	2.16	2.15	3.46
	O	1.11	1.17	1.24	2.04

they differ significantly. Thus, these coincidences of the Mulliken and Löwdin results can be regarded as casual. And since the nine-plane slab does not provide the bulk-like electron density in the middle of the slab, the correspondence between

the values for the covalences of the bulk and slab atoms, obtained by the traditional population analysis schemes, also cannot be considered as reliable.

The WTAO method, in its turn, allows one to obtain the values of atomic covalences in the slab, which can be physically interpreted. First, the values calculated with the orthogonal and nonorthogonal WTAOs are alike. Secondly, the in-slab atoms have a covalence different from the bulk one. This result can be expected due to an insufficient thickness of the nine-plane slab for the TiO_2 (110) surface modeling.

And last but not least, the results of the WTAO population analysis clearly show the increase of the covalence at the surface of the slab when compared to the in-slab values. The surface atom O1 has the maximal covalence among all the oxygen atoms of the slab. This effect is even sharper if it is remembered that this atom is only two-coordinated, while the others are three-coordinated. The large value of the covalence is also observed for the surface atoms O2/O3, but it is not as pronounced as for the atom O1. The atom Ti1, which can be regarded as a surface atom, has a smaller covalence than the atom Ti2, but taking into account that the former is only five-coordinated, one can conclude that the effect of higher covalence at the surface is valid for this atom as well.

The values of local characteristics of the slab electronic structure, differing from the bulk one, may indicate the possibility of significant structural relaxation of the studied TiO_2 slab. This relaxation would involve in-surface and intraslab atoms, since the TiO_2 nine-plane slab at its inner planes does not reproduce the bulk electronic structure. Taking into account the results of the WTAO population analysis, one can assume that the atoms would shift so that the length of the bonds would increase or decrease to compensate the excessive or deficient values of the covalence, respectively. These considerations correlate with the studies of the geometry optimization in TiO_2 slabs [765].

11.2 Surface LCAO Calculations on TiO_2 and SnO_2

11.2.1 *Cluster Models of (110) TiO_2*

Titanium dioxide (in rutile and anatase structures) is the most investigated crystalline system in the surface science of metal oxides. The review article [766] summarizes the results of experimental and theoretical studies of titanium dioxide (bulk and surface) made up to 2002 inclusive. The information about calculations of the surface reconstruction, surface defects, and growth of metals on TiO_2 is also included. The results of the later theoretical studies of rutile surfaces can be found in [767–778] and references therein. In the majority of the calculations, the slab model was used for the study of periodic surface structures.

Here, we consider the molecular- and cyclic-cluster models of (110) TiO_2 , following [753], where the connection between the slab and cluster models was considered by performing a symmetry analysis of the crystalline surface.

The cyclic-cluster (CC) model of the surface is connected to the slab-2D-supercell approach, but it is different due to the different introduction of cyclic boundary conditions (CBCs). In the slab-supercell approach, these conditions are, in fact, introduced for a very large system, *for example*, for the main region of the 2D periodic plane lattice, so that band-theory methods can be used in the slab calculations. In the CC model, the CBCs are introduced for the cluster itself, so that the model turns out to be finite. The convergence of the results to the slab values must be investigated by increasing the CC. However, the CC approach offers evident advantages: (a) the spurious boundary effects of molecular clusters are absent; (b) the periodicity of adsorbed species or of defects is excluded because the CC is a finite system; (c) there is a one-to-one symmetry correspondence between the electronic states of the 2D CC and the band states of the corresponding slab model.

The CC model was applied in semiempirical calculations [779] of the adsorption geometry for organic adsorbates on a rutile (110) surface. The INDO parametrization scheme was modified to reproduce the experimental results for geometries of carbon- and nitrogen-containing molecules. The CC representing the rutile (110) surface consists of 120 atoms. It includes two layers of 5×2 2D unit cells with six atoms in each 2D unit cell. It is seen from Fig. 11.6 that 2D primitive unit cells form a plane rectangular lattice with parameters c and a (a, c are the tetragonal lattice parameters of the bulk crystal).

The molecular-cluster (MC) model is extremely popular in surface simulations because of its simplicity and flexibility and the possibility of its use in the standard techniques of molecular quantum chemistry [310, 752]. It is also possible to study defects or adsorption reactions in the limit of low coverage. In the MC approach, a crystal with a surface is modeled by a finite (molecular) system consisting of atoms on the surface and of some atomic planes nearest to it. The 2D periodicity of the surface is disregarded so that the symmetry of such a model is described by one of the crystallographic point groups. In adsorption studies, the adsorbed species are included in the cluster-adsorbate systems. An MC is cut out of the slab to simulate a portion of the surface so that spurious effects arise that are related to the limited cluster size and to the presence of the boundary. To eliminate these effects, the dangling bonds are saturated either by hydrogen atoms or pseudoatoms or the whole cluster is placed in an external field simulating the influence of the bulk crystal [752].

In the MC model, the results critically depend on the choice of the cluster size, stoichiometry, and shape. Nevertheless, the MC model can provide useful information if the cluster is properly chosen and the influence of its size is investigated. A number of general rules were suggested in [753, 754] for the generation of an MC suitable for surface simulations based on the connection between the MC and the slab model. These rules have been intuitively applied in different studies, in most cases without explicitly considering the relationship between periodic and molecular models. The following rules allow artifacts of MC

surface models to be minimized: (a) the clusters correctly reflect the stoichiometry of the bulk crystal and are electroneutral; (b) atoms on the crystal surface should be equivalent to those on the cluster surface except for corners and edges; (c) the average coordination of all cluster atoms is as close as possible to that of atoms on the crystal surface; (d) as many symmetry elements of the crystal surface as possible are retained in the cluster; and (e) an extension to rule (a) is that each layer of the cluster should have the stoichiometry of the crystal.

In fact, such principles of the MC choice ensure the simulation of the crystal surface as closely as possible and are directly connected with the 2D-periodic-slab model. By using 2D unit cells as basic units of the model clusters, it is possible to increase the cluster size in a systematic way and, thereby, to study the convergence behavior of calculated surface properties. As examples of MC model applications to surface studies using some of the above-mentioned rules, calculations of MgO , TiO_2 (rutile, anatase structures), and Cr_2O_3 (corundum structure) surfaces and adsorption of small molecules on them can be considered, see [753] and references therein. However, it is also possible to find examples in the literature where these rules have not been applied and, in part, unphysical results were obtained.

In MgO and NaCl crystals, the MCs were chosen [780] so that they simulated the 2D supercell of the surface and included several layers of the bulk crystal. For these crystals, the stoichiometry of the chosen MC was ensured by this choice.

For more complicated systems, *for example*, TiO_2 structures, the stoichiometry of the MC is only ensured when several additional oxygen atoms are added. There are two principle ways to add these additional atoms. They can be placed on the regular surface around the cluster. This is denoted as type A in Figs. 11.9 and 11.10.

In some cases, this procedure leads to clusters that do not correspond to rules (d) and (e). Another possibility is to place the additional atoms for saturation at irregular positions of the crystalline lattice so that rules (d) and (e) will be fulfilled. Examples of this second type (B) of cluster generation are presented in Figs. 11.9 and 11.10.

If all layers of a multilayer cluster have the same stoichiometry, artificial polarization, which can affect the calculated surface properties, is reduced. To study the effect of the distribution of saturation atoms on the calculated properties of crystalline surfaces, the rutile (110) surface has been selected for the MSINDO calculations [753]. The water adsorption in the molecular and dissociated form was modeled on clusters of Ti_5O_{10} , Ti_9O_{18} , $\text{Ti}_{14}\text{O}_{28}$, and $\text{Ti}_{18}\text{O}_{36}$ (Fig. 11.9) chosen according to the rules given above. Nevertheless, even if these rules are applied, several different types of clusters can be constructed. Two types of possible cluster models were used. In type A clusters, additional oxygen atoms, necessary to ensure total stoichiometry (shaded in Fig. 11.9), were placed at regular lattice positions. In type B clusters, additional oxygen atoms were placed at nonlattice positions to maximize the symmetry of the clusters and to reduce polarization, as discussed in the previous section.

The adsorption energies calculated with these small cluster models are presented in Table 11.10. The geometries of the clusters were optimized within the symmetry of the rutile structure. In model B, there are one or two more degrees of freedom for oxygen atoms in nonlattice positions.

Fig. 11.9 Rutile (110) surface of size 1×1 : 1–4 layer clusters of types A and B, [753]. Black, white, and shaded spheres label Ti, O, and additional O atoms

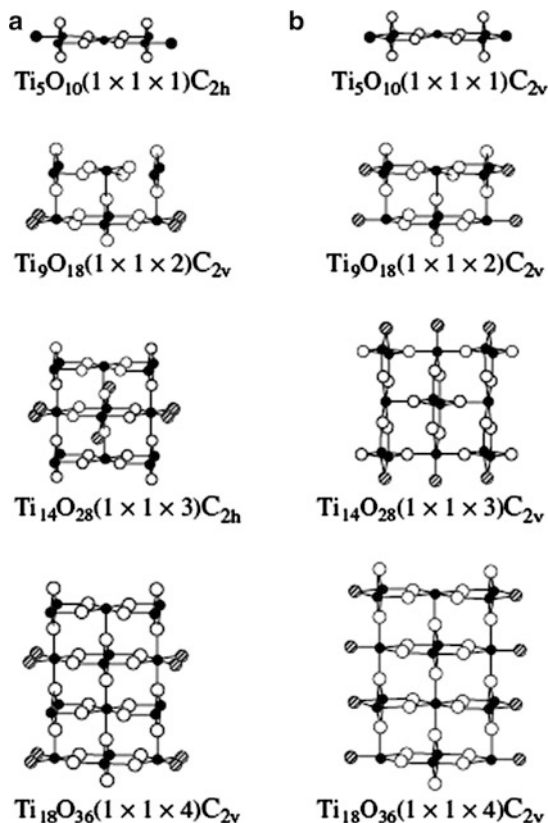


Table 11.10 MSINDO adsorption energies (kJ/mol) for water adsorption on rutile (110) (relaxed cluster calculations), [753]

Cluster	Type A		Type B	
	Molecular	Dissociative	Molecular	Dissociative
Ti ₅ O ₁₀	51	39	70	201
Ti ₉ O ₁₈	139	−24	94	107
Ti ₁₄ O ₂₈	66	8	92	143
Ti ₁₈ O ₃₆	157	192	129	162
Ti ₄₉ O ₉₈	120	151	119	157

For the cluster–water systems, the Cartesian coordinates of all water atoms, the two surface atoms close to the oxygen atom, and the hydrogen atom of water are optimized. The adsorption energy is calculated as the difference in the total energies of the TiO₂ cluster and the cluster+H₂O system. Therefore, positive values indicate stabilization. A comparison is made with the results of the calculations on a much larger cluster, Ti₄₉O₉₈ (Fig. 11.10), which is a better representation of the surface.

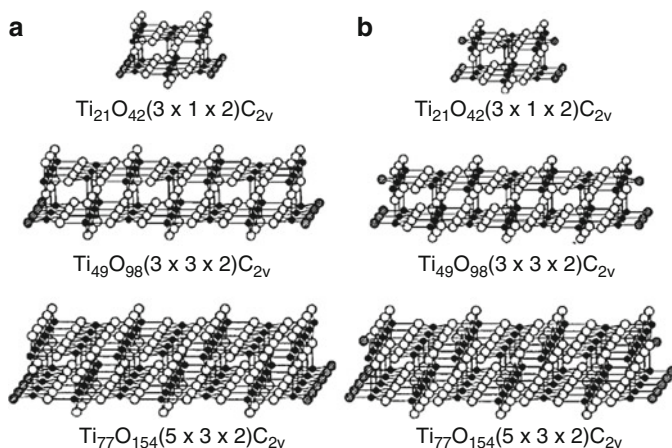


Fig. 11.10 Rutile (110) surfaces of size 3×1 , 3×3 and 5×3 : two-layer clusters of types A and B, [753]. The labels of atoms are the same as in Fig. 11.9

From Table 11.10, it can be seen that the different distribution of additional oxygen atoms in clusters A and B has a substantial influence on the calculated adsorption energies. The variation of adsorption energy with an increasing number of layers is significantly reduced if model B is considered. Even for rather small systems, the adsorption energies are relatively close to that of the largest cluster, $\text{Ti}_{49}\text{O}_{98}$. The most important difference between the two models is that only for model B is the dissociative adsorption always more stable than that of the molecular form. The relative stability of the two forms of water on the rutile (110) surface is still a matter of debate (see the next section). At the moment, we only focus on the convergence of results obtained for clusters with increasing sizes.

A comparison of models A and B of the largest cluster ($\text{Ti}_{49}\text{O}_{98}$) shows that the influence of additional atoms is negligible due to their large distance from the adsorption position. This indicates that, in this case, it is the description of the local environment near the adsorption site rather than the effect of the global polarization of the cluster that is responsible for the differences observed for the smaller clusters. Thus, the numerical results for the adsorption behavior of rutile (110) toward water with different clusters demonstrate that convergence to the methodological limit is significantly improved if the criteria mentioned above are taken into account.

Since the underlying considerations are of a general nature, they can also be applied to cluster models of surfaces in other systems. In any case, only the comparison of the results of both slab and cluster model application allows those results of calculations that can be taken as confident to be extracted. In the next section, we consider this point returning to the water adsorption on the (110) surface of rutile.

11.2.2 *Adsorption of Water on the TiO₂ (Rutile) (110) Surface: Comparison of Periodic LCAO–PW and Embedded-Cluster LCAO Calculations*

The adsorption of water on TiO₂ surfaces has been extensively investigated using both experimental and theoretical methods, see [773] and references therein. Nevertheless, the adsorption of H₂O on the TiO₂ (110) surface is still a matter of controversy. From experiments, it has been proposed that H₂O adsorbs mainly associatively and dissociates at defect sites, see [781] and references therein. If dissociation does occur, it is only at low coverages (<15%) that may be associated with surface defects. In contrast, most DFT 3D periodic calculations with the plane-wave (PW) basis predict dissociation at all coverages or an equivalent amount of dissociative and associative mechanisms. In contrast, Hartree–Fock (HF) embedded-cluster calculations with an atomic (Gaussian) basis set [784] predict that the associative mechanism should be favored due to overestimation of H-bonding in the dissociated configuration by DFT–PW studies.

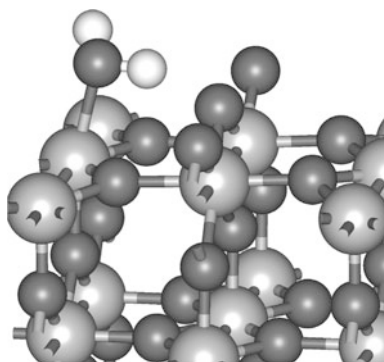
The first two-periodic all-electron HF LCAO calculations of the rutile relaxed surfaces, made in [762], gave atomic displacements of surface atoms that did not differ significantly from the later results of DFT–PW investigations. Further periodic LCAO studies of TiO₂ bare surfaces have been made in [760, 782, 783]. For studies of H₂O adsorption on TiO₂, the single-slab periodic HF LCAO and DFT LCAO methods were first applied in [773] and compared with PW–DFT results to test various methods with cyclic- and embedded-cluster calculations and resolve discrepancies between the methods.

In the discussion of numerical results of this study, we use the following labels for atoms of the (110) TiO₂ shown on Fig. 11.6: Ti₁, Ti₂–Ti_{5f}, Ti_{6f} (five- and sixfold coordinated titanium atoms), O₁, O₂–O_{br}, O_{3f} (bridging and threefold coordinated oxygen atoms).

Both in 2D (single-slab) LCAO and 3D (periodic-slab) PW calculations, the same 3-layer (9 atomic planes) slab was used with the fixed positions of the middle-layer atoms. Both associative (molecular) and dissociative water monolayer adsorptions have been investigated.

DFT–PW calculations were performed on different H₂O–TiO₂ structures to determine which one corresponds to the most stable arrangement on the rutile (110) surface. To this end, a 3D supercell consisting of 1×1 or 2×1 surface unit cells was used to model the (110) surface geometry. The smallest surface unit cell was chosen for bare-surface calculations, having dimensions of $|\mathbf{c}|$ (2.959 Å) and $\sqrt{2}|\mathbf{a}|$ (6.497 Å) in the (001) and (-110) directions, respectively, where $\mathbf{a}$ and $\mathbf{c}$ are translation vectors for the bulk rutile unit cell. This surface unit cell is doubled in the (001) direction for the hydroxylated or hydrated surfaces. The calculations were performed for 3-layer slabs with a total cell thickness ≈ 19 Å, *that is*, slab thickness + vacuum gap 10 Å. A model with the fixed atomic positions of the central layer is assumed to be more appropriate to the real 2D surface relaxation because real crystals are not thin films and the bulk-crystal structure probably exists a few

Fig. 11.11 Associative (molecular) adsorption at half-monolayer coverage



atomic layers beneath the mineral surface. Use of the constrained central layer was also accompanied by imposition of the inversion symmetry. This symmetry saves computational time and minimizes any possible dipole moment of the slab.

Adsorption was simulated with a pair of H_2O molecules (one at each side of the 3-layer TiO_2 slab) using a 2×1 unit cell. The use of one H_2O molecule on each side allows a cell with inversion symmetry to be used and creates a system with zero dipole moment associated with the slab.

In a PW study of water *associative adsorption* (with structure optimization), it was found that the lowest energy corresponds to the following structure: the water O is directly bonded to the five-coordinate Ti_{5f} -atom, a single H-bond between an H in H_2O and a bridging oxygen atom (O_{br}) and the torsion angle $\text{H} - \text{O} - \text{H} \cdots \text{O}_{\text{br}}$ 117° , see Fig. 11.11. In the structure with an angle of 180° , all atoms of the water molecule and bridging oxygen are in the same plane, but this structure appears to be less favorable.

The *dissociative adsorption* of H_2O onto the (110) surface was modeled assuming that one H atom was bonded to the O_{br} next to the Ti atom with a terminal OH group. (Note that this Ti atom was originally 5-coordinated on the bare (110) surface.) Due to the half-monolayer configuration, the neighboring OH groups can be adsorbed either in a zigzag geometry or inline. In the latter case, there exists the possibility of H-bonding between neighboring bridging and terminal OH groups: $\text{O}_{\text{br}} - \text{H} \cdots \text{O}_{\text{ter}} - \text{H}$. Consequently, the inline configuration only was considered because this H-bonding should lower the adsorption energy. As in the case of molecular H_2O adsorption, there are two possible OH orientations: in-plane, with torsion angle $\text{H} - \text{O} \cdots \text{H} - \text{O}$ equal to 180° (structure 1, Fig. 11.12), and a conformation with smaller torsion angle (structure 2, Fig. 11.13).

Energy minimizations of the corresponding slabs led to similar adsorption energies for both structures, which were lower than the corresponding associative values for 1/2 monolayer coverage by $\approx 3\text{--}5$ kcal/mol. Thus, these results are in accordance with previous DFT simulations for half-monolayer coverage that predict H_2O dissociation on the rutile (110) surface.

Fig. 11.12 Dissociative adsorption, half-monolayer coverage: structure 1, view in (001) direction

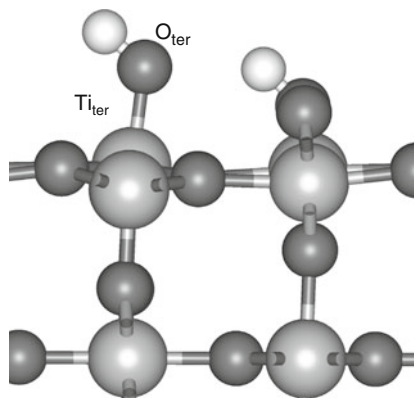
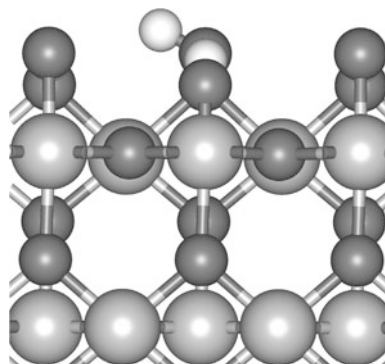


Fig. 11.13 Dissociative adsorption, half-monolayer coverage: structure 2, view in (1-10) direction



A different conclusion was obtained from calculations on models corresponding to full-monolayer coverages. The distinct feature of these structures, in contrast to other cases, is the nearly equivalent displacements of the Ti and O atoms on the surface Ti layer such that they lie in one plane. Also, it is interesting to note that the overall arrangement of H and O atoms in the (110) surface is similar in both associative and dissociative adsorption. The obtained binding energies are stronger for associative adsorption on both the 3- and 5-layer slabs. This size of difference (3.6 kcal/H₂O molecule) in favor of associative adsorption was not obtained in previous DFT calculations.

In Table 11.11, the adsorption energies, obtained in PW calculations, are compared with those obtained in LCAO HF and DFT calculations for the structures, optimized in PW–DFT calculations. The computational details of both PW and LCAO calculations are given in [773].

In Table 11.12, n Ti-L designates the number of Ti planes in the slab model; DB ECP means Durand–Barthelat effective core potential for Ti atoms,[468]. As can be seen, the HF method using both all-electron and ECP bases gives the dissociative adsorption energies that are about 2–3 kcal/mole more favorable than those for associative adsorption. The DFT method results in the opposite picture: associative

Table 11.11 Calculated (without zero-point correction) at monolayer coverage and experimental adsorption energies (per one water molecule) for H₂O/TiO₂(110) (kcal/mol), [773]

Method	Molecular adsorption	Dissociative adsorption
PW:DFT-GGA-PW91, 340 eV; 3 Ti-L	−24.9	−23.0
PW:DFT-GGA-PW91, 340 eV; 3 Ti-L (Monkhorst–Pack k -point set 3 3 1)	−24.7	−22.7
PW:DFT-GGA-PW91, 1,000 eV; 3 Ti-L (Monkhorst–Pack k -point set 3 3 1)	−25.2	−24.6
PW:DFT-GGA-PW91, 340 eV; 5 Ti-L	−22.0	−18.4
PW:DFT-GGA-BP88, 1,000 eV ^a	−18.9	−24.9
PW:DFT-GGA-PW91, 750 eV ^b	−22.8	−21.0
LCAO:HF, DB ECP; 3 Ti-L	−35.63	−37.27
LCAO:HF, DB ECP; 3 Ti-L, with equal basis on all species (for BSSE)	−28.25	−28.91
LCAO:HF, all-electron; 3 Ti-L	−28.32	−31.39
LCAO:DFT-GGA-PW91, DB ECP; 3 Ti-L	−40.74	−36.42
LCAO:DFT-GGA-PW91, DB ECP; 5 Ti-L	−35.15	−30.20
Experiment ^c	−(14–24)	–

^a[792]^b[786]^c[781]

adsorption energies exceed the dissociative values by approximately 5 kcal/mole both for the 3 and 5 Ti-layer slabs.

The basis-set superposition error was estimated for ECP 3 Ti-layer hydroxylated slabs, and it appears to be 6.4 kcal/mole per water molecule. The TiO₂ slabs with the dissociated and molecular form of H₂O have been calculated using exactly the same basis sets in all cases, so the large value of BSSE influences the absolute values of ΔE only, but not the relative energy of water dissociation on the TiO₂ surface. Taking into account the value of BSSE, the absolute values of the obtained LCAO water-adsorption energies seem to lie in the interval of 25–35 kcal/mole that is slightly greater than the corresponding PW results.

The *z*-shifts of positions of the surface atoms on TiO₂ slabs obtained by LCAO methods are given in Table 11.12.

The optimized geometry of a bare TiO₂ surface and of hydroxylated (hydrated) slabs exhibits qualitatively the same relaxations in LCAO calculations as were found in PW calculations. But there are some quantitative differences between the results of the DFT–PW, DFT LCAO, and HF LCAO approximations. It appears that the Kohn–Sham Hamiltonian (both on the PW and LCAO bases) produces the larger expansion of the slabs toward the vacuum, making them thicker, and thus affects the vertical displacements of atoms to be more positive relative to HF and experimental values. The same effect was found for hydroxylated and hydrated species: horizontal and vertical distortions of top-surface oxygens and titaniums from their bulk positions are substantially larger for DFT LCAO than for HF LCAO.

Table 11.12 z -shifts (Å) of Ti and O atoms on the bare surface of (110) rutile 3 Ti-layer models obtained by LCAO calculations, [773]

Method→ Atom type (symbol)↓	HF, all- electron	HF, DB ECP	DFT, DB ECP	HF, all- electr. [762]	Exp. [787]
Sixfold coordinated surface Ti (Ti_{6f})	0.13	0.15	0.19	0.09	0.12 ± 0.05
Fivefold coordinated surface Ti (Ti_{5f})	-0.12	-0.12	-0.09	-0.15	-0.16 ± 0.05
Bridging surface oxygen (O_{br})	-0.07	-0.07	0.01	-0.14	-0.27 ± 0.08
Threefold coordinated surface oxygens (O_{3f})	0.15	0.14	0.21	0.07	$0.05/0.16 \pm 0.08$
Oxygen underneath O_{br} (O_{uO})	-0.02	-0.02	-0.01	-0.07	0.05 ± 0.08
Oxygen underneath Ti_{5f} in the middle Ti-layer (O_{uTi})	-0.01	0.01	0.03	-0.02	0.00 ± 0.08

Also, the DFT method leads to more flexible hydroxyl groups on hydroxylated surfaces and, as a consequence, to shorter H-bonds between them.

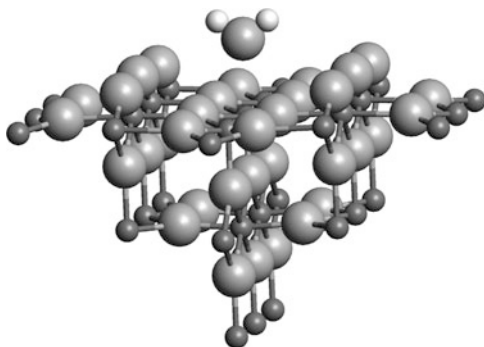
The LCAO basis gives the possibility to calculate atomic charges in a more direct way than the PW basis. It was found in [773] that the values of Mulliken charges lie in a reasonable region and reflect the partially covalent nature of chemical bonds in titanium oxides, although the HF method gives absolute values about 25% larger than the DFT method. The deviations of atomic charges on the surface of unhydroxylated slabs from their bulk values, generally, were less than $0.1 e$ both for Ti and O atoms, except the charge on the bridging oxygen obtained in DFT calculations that was reduced by more than $0.2 e$. It is interesting to note that oxygen charges in hydroxylated and hydrated slabs become less negative in the order: $|q(\text{O}_{br})||q(\text{O}_{3f})| > |q(\text{O}_{\text{H}_2\text{O}})|$, which is correlated with the acidity of the corresponding hydroxyls.

Tables 11.11 and 11.12 demonstrate the relatively large dependence of the calculated water-adsorption energies on the nature of the quantum-mechanical approximation (HF or DFT) and type of basis set (PW or LCAO) within the same periodic-slab model. It should be noted that the results for the equivalent 2D- and 3D-slab models coincide if the sufficiently large vacuum gap for 3D model is used, see Sect. 11.1.3. Nevertheless, we can conclude that the Kohn–Sham Hamiltonian using both PW and LCAO basis sets gives the order of the adsorption energy that is in better agreement with the experimental observations. However, the relaxation of the surface atoms seems to be more appropriate to experimental data [787] in the case of the HF calculations.

The long-term goal of research [773] was to model the interface of TiO_2 and bulk water, so solvation forces will need to be included to predict adsorption energies and surface structures. Solvation forces are difficult to include in periodic DFT calculations because a large number of H_2O molecules must be included

Fig. 11.14

Embedded-cluster results for the HF geometry of $\text{Ti}_{17}\text{O}_{34} - \text{H}_2\text{O}$: associative adsorption [773]. Small-sized balls represent the Ti pseudopotential cores



in layers between rutile slabs to simulate bulk water. On the other hand, the HF embedded-cluster approach in the program CECILIA [784] can include H-bonding to H_2O molecules not directly bonded to the surface and long-range solvation via a dielectric continuum half-space representing bulk water. The embedded-cluster approach is one obvious way to develop a force field for the $\text{Ti}-\text{O}-\text{H}$ system representing the real $\text{TiO}_2-\text{H}_2\text{O}$ interface [774], so consistency between this approach and the results of periodic calculations would be a useful step toward reliable molecular-dynamics simulations of the larger-scale rutile–water system.

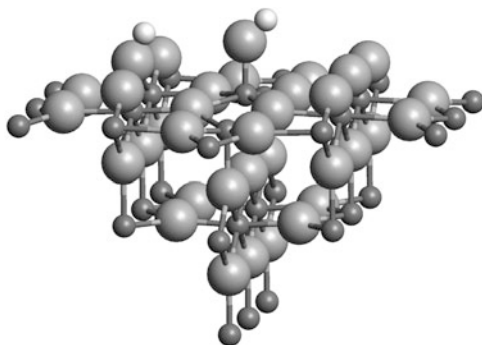
Embedded-cluster calculations have been made for comparison with periodic studies using the model developed in [784]. This model utilizes a three-level interaction approach and takes into account the long-range forces properly. The central stoichiometric part of the cluster is treated by the *ab initio* LCAO method using pseudopotential cores of extra Ti atoms to saturate the dangling bonds of the outermost oxygen atoms. A large stoichiometric grid of point charges represents the surrounding ions, and a special array of point charges distributed on a closed surface around the cluster is constructed to reproduce the remainder of the long-range Coulomb interactions (*i.e.*, the Madelung potential of the bulk crystal at the surface). The neutrality condition is satisfied separately for the stoichiometric part of the cluster and lattice array of ions plus extra pseudopotential cores.

Embedded-cluster calculations were carried out on stoichiometric clusters of different sizes: Ti_7O_{14} , $\text{Ti}_{13}\text{O}_{26}$, and $\text{Ti}_{17}\text{O}_{34}$ (the largest cluster is shown in Figs. 11.14 and 11.15).

In the Ti_7O_{14} and $\text{Ti}_{13}\text{O}_{26} - \text{H}_2\text{O}$ clusters, only one Ti, one bridging O, and the H_2O atoms were allowed to relax during energy minimization. In contrast, the additional 4 oxygen atoms (nearest to the central Ti) were free to move in the $\text{Ti}_{17}\text{O}_{34} - \text{H}_2\text{O}$ cluster. The larger cluster and greater surface relaxation were considered necessary to adequately describe the possible H-bonding arrangements of associatively and dissociatively adsorbed H_2O on the TiO_2 (110) surface. About 1,000 full-point charges (*i.e.*, +4 and –2) from the 4 Ti-layer slab and up to 310 partial charges fitted to the Madelung potential of the rest of the crystal were introduced to represent the electrostatics of the bulk TiO_2 . The positions of cluster atoms and lattice ions were chosen in accordance with the experimentally

Fig. 11.15

Embedded-cluster results for the HF geometry of $\text{Ti}_{17}\text{O}_{34} - \text{H}_2\text{O}$: dissociative adsorption [773]. Small-sized balls represent the Ti pseudopotential cores

**Table 11.13** Embedded-cluster results (without BSSE) [773] and experimental adsorption energies for $\text{H}_2\text{O}/\text{TiO}_2$ (110) (kJ/mol)

Method	Cluster	Molecular adsorption	Dissociative adsorption	Reference
LCAO:HF,LANL1	$\text{Ti}_{17}\text{O}_{34}$	-94 ^a	-48 ^a	[773]
LCAO:HF,LANL2	$\text{Ti}_{13}\text{O}_{26}$	-158	-90	[773]
LCAO:HF,LANL1	Ti_7O_{14}	-137 ^b	-31 ^b	[788]
LCAO:B3LYP,LANL1	Ti_7O_{14}	-146	-95	[788]
Experiment		-(59–100)		[781]

^aEstimated BSSE is about 35 kJ/mol.

^bEstimated BSSE is about 29 kJ/mol.

determined surface relaxation [787]. For embedded-cluster HF LCAO calculations, the Hay–Wadt LANL1 or LANL2 [467] pseudopotentials for Ti atoms and SBK [469] pseudopotential on O atoms and corresponding basis sets have been used. In the case of LANL1, the $3s$ and $3p$ electrons of the Ti atom are included in the atomic core, whereas in the case of LANL2, the corresponding orbitals are treated as semicore states. For the pseudopotential cores of Ti atoms saturating the dangling bonds, only the semicore basis functions were included in the case of the LANL2 pseudopotential, whereas in the case of the LANL1 pseudopotential, the basis functions were not included. This trick provides the same net charge on the extra pseudopotential Ti cores as on the lattice ions.

The embedded-cluster results for water-adsorption energies are given in Table 11.13. This table demonstrates the dependence of the embedded-cluster results on the cluster size, basis set, and Hamiltonian used. When the size of the cluster is increased, the energy difference between the associative and dissociative adsorption mechanisms decreases.

The results for embedded-cluster calculations are different from that for the periodic models. Adsorption energies of a water molecule in the cluster case were much more favorable for the associative mechanism (Table 11.13), which is in better agreement with experimental observations. The predicted adsorption energies for the associative mechanisms are higher than the measured values. There is no significant difference between the optimized geometry for water adsorption in $\text{Ti}_{13}\text{O}_{26}$ and $\text{Ti}_{17}\text{O}_{34}$; the structures of the largest one are shown in Figs. 11.14 and 11.15.

No evidence of H-bond interactions was found in either the dissociative or associative adsorption structures in contrast to periodic PW and LCAO calculations. Bridging oxygen atoms in the cluster model appear to exhibit less relaxation than in periodic slabs.

The reason for such divergence between the periodic and cluster approaches is not entirely clear. The most probable reason is the differences in symmetry and boundary conditions: the absence of periodic boundary conditions may lead to artificial rigidity of the Ti–O bonds. Also, assigning of formal charges to lattice ions may overestimate the Madelung potential of the bulk crystal in the cluster model. On the other hand, the 3- and 5-layer periodic models apparently overestimate the surface relaxation, and the thicker-slab models are needed for improved quantities.

The results obtained in [773] correspond well with the experimental observation that the probability of H_2O dissociation is increased with decreasing coverage. One explanation of this change in mechanism with coverage is that H_2O molecules can readily align to provide the maximum H-bonding interaction in associatively adsorbed structures. At low coverages, H-bonding energies are not as significant as at higher coverages, so the additional energy of forming stronger Ti–OH bonds (as compared to Ti–OH₂ bonds) outweighs the H-bonding term and dissociation may dominate.

Applying the different *ab initio* quantum-mechanical approximations (DFT–PW, DFT LCAO, or HF LCAO) within the periodic models produces qualitatively close results, but disagreement may exist in reproducing the difference between close values if this difference is about several kcal/mole. In particular, the DFT LCAO method gives the order of the associative and dissociative water-adsorption energy that is in better agreement with the experimental observations. Additional investigations of H-bonding between water molecules and oxygen atoms on the TiO_2 surface using both DFT and HF methods should be made to resolve the disagreement between the periodic and embedded-cluster calculations.

The additional information about the water-adsorption mechanism can be obtained in calculations of the oxides with the same bulk structure but different metal atom. The results of water adsorption on SnO_2 surfaces is discussed in the next section.

11.2.3 *Single-Slab LCAO Calculations of Bare and Hydroxylated SnO_2 Surfaces*

Cassiterite (SnO_2 in rutile structure)-based materials are extensively studied due to their gas-sensing properties. The theoretical modeling of the surface processes plays an important role in this research.

The first-principles methods have made an increasingly significant contribution to understanding the nature of clean SnO_2 surfaces [789–791] and the interaction of these surfaces with adsorbed water [792–794], methanol [795], CO [796, 797],

Table 11.14 Calculated equilibrium crystallographic parameters, valence-band width, and bandgap for the bulk rutile SnO₂ crystal [799]

Parameter	Experiment	LCAO DFT calc.[799] ^a		LCAO DFT calc.		PW DFT calc.	
		B3LYP	PBE	B3LYP[798]	LDA[800]	PW91[790]	PW91[801]
<i>a</i> (Å)	4.737	4.690	4.745	4.718	4.714	4.778	4.731
<i>c</i> (Å)	3.186	3.147	3.185	3.187	3.241	3.232	3.157
<i>c/a</i>	0.673	0.671	0.671	0.675	0.688	0.676	0.667
<i>u</i>	0.306	0.307	0.307	0.307	0.307	0.306	0.306
VB width (eV)	7.5–9.0 [803]	8.56	8.24	9.0	–	–	6.5
BG (eV)	3.6[804]	4.03	1.56	3.30	–	–	1.15

^a Calculated Fermi-energy level: -4.73 eV (B3LYP) and -4.01 eV (PBE). Experimental estimation: -4.35 eV [802]

and O₂ [798] molecules. Many of these calculations use the DFT–PW periodic-slab model. The LCAO single-slab approach has been successfully applied for investigation of cassiterite [789, 795–798]. A review of both PW and LCAO studies of adsorption on the perfect and reduced surfaces of metal oxides can be found in [767].

We discuss here the results of LCAO calculations [799] based on both plain DFT PBE and hybrid B3LYP Hamiltonians to investigate the surface relaxation and adsorption of water molecules on the stoichiometric (110) and (100) SnO₂ surfaces. The aims of this study can be summarized as follows: (1) comparison of the plain DFT functionals with the B3LYP hybrid functional for the surface modeling; (2) analysis of the energetic and structural adsorption properties of the stoichiometric (110) and (100) SnO₂ surfaces (the latter was not studied before); and (3) finding the difference in the adsorption of water on (110) and (100) surfaces.

Table 11.14 gives the comparison of calculated and experimental structure parameters (*a*, *c*, *u*), valence-band (VB) width, and bandgap (BG) for bulk SnO₂ in rutile structure. As can be seen in Table 11.14, the LCAO-calculated values are in reasonable agreement with the experimental data and the results of DFT–PW computations. The B3LYP form of GGA slightly underestimates the cell dimensions, whereas the PBE functional gives values that are closer to the experimental data. The minor discrepancies between the results of B3LYP calculations [799] and [798] may be due to the different form of pseudopotentials (Hay–Wadt in the first case and Durand–Barthelat in the second case) taken. The theoretical valence-band (VB) width (of 8.56 eV using B3LYP and 8.24 eV using PBE) agrees well with the experimental data [804] of 7.5–9.0 eV. As expected, the B3LYP method gives the bandgap (BG) of 4.0 eV that is close to the experimental value of 3.6 eV [804]. The differences between the various PW–DFT calculations reported in Table 11.14 are obviously due to the computational details (choice of pseudopotentials, cutoff energy, and others). In all cases, the plain DFT methods produce a bandgap that is about 2–3 times narrower than the experimental value. The valence-band density of

Table 11.15 Calculated energy per unit area of the (110) and (100) surfaces of SnO₂ crystal [799]

Surface	cell	k-set	Number of atomic planes /Sn ₂ O ₄ layers	Surface energy (J/m ²)			
				PBE		B3LYP	Ref.data
				unrelaxed	relaxed	relaxed	relaxed
110	1 × 1	6 × 3	9/3	1.70	1.29		1.45 [801]
			15/5	1.69	1.26 (1.14) ^a	1.40	1.04[790] ^b
100	1 × 1	6 × 4	12/2	1.74	1.37		–
			15/2.5	1.73	1.37 (1.26) ^a	1.48	1.14[790] ^b

^aBSSE-corrected values are given in parentheses.^b5–6 Sn₂O₄ layers have been used in [790] for estimation of the surface energy.

electronic states (DOS) in bulk crystal calculated using the B3LYP functional [799] shows the well-known fact that oxygen *p*-states give the main contribution to the VB DOS, whereas the tin *s*- and *p*-states form the bottom of the conduction band.

From the results of PW–DFT periodic-slab calculations [790], the cassiterite (110) and (100) type 2 surfaces are the most stable of the low-index faces, and hence, they should be the dominant crystallite arrangement of SnO₂.

To check this by the single-slab approach, LCAO calculations of the stoichiometric slabs (consisting of a whole number of SnO₂ formula units) have been used for surface modeling [799]. As in the rutile TiO₂ case, the distribution of the bulk unit cell six atoms over atomic planes depends on the surface chosen: (110) O–Sn₂O₂–O; (100) O–Sn–O–O–Sn–O (see Fig. 11.3). The bridging oxygen atoms O_{br} terminate both surfaces; two bonds connect them with the sixfold Sn (Sn_{6f}) atoms on the rutile structure surfaces. There are fivefold tin atoms (Sn_{5f}) with one unsaturated bond and threefold oxygens (O_s) in the atomic plane next to O_{br}, see Sect. 11.2.2 and Fig. 11.6. The positions of all the atoms in slabs were allowed to relax at a fixed dimension of the 2D surface unit cell that was taken from the bulk optimization result. The surface energy was calculated using (11.8) for three- and five-layer slabs for a (110) surface (9 and 15 atomic planes), and two- and 2.5-layer (12 and 15 atomic planes) slabs for a (100) surface to check the convergence of the surface energy with *n* in the DFT (PBE) LCAO calculations. The influence of the basis-set superposition error (BSSE) on the calculated values has also been estimated. For this purpose, three extra atomic layers of ghost atoms have been added on each side of the relaxed slabs and the total energy was recalculated.

The obtained surface energies are given in Table 11.15. Table 11.15 demonstrates that for both DFT (PBE) LCAO and hybrid B3LYP LCAO methods, a (110) surface is more stable than a (100) surface, in accordance with PW–DFT calculations [790]. Comparing the surface energies in Table 11.15 before relaxation, we see that they are approximately the same for both surfaces. So, apparently, it is relaxation that provides the larger relative stability of the (110) surface. The B3LYP surface energies are larger than the corresponding PBE values by about 0.1 J/m². On the

Table 11.16 Widths of electronic bands and Fermi energy (eV) for bulk SnO₂ and for the different surface models (B3LYP results; AH—associatively hydroxylated, DH—dissociatively hydroxylated) [799]

Band	Surfaces						
	Bulk	(110)			(100)		
		clean	AH	AD	clean	AH	AD
VB width	8.56	9.24	8.45	8.56	8.34	8.23	8.61
BG	4.04	3.14	4.22	4.29	4.07	4.45	4.54
E_{Fermi}	-4.73	-8.38	-7.22	-8.11	-9.24	-7.07	-7.39

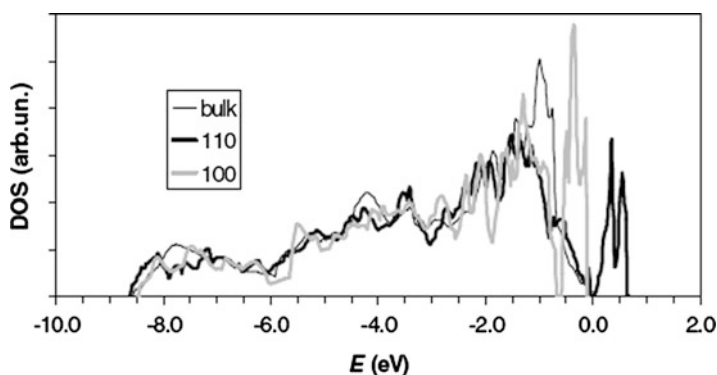


Fig. 11.16 Total valence-band DOS of bulk SnO₂ crystal (*fine line*), its (110) (*bold dark line*) and (100) (*bold gray line*) surfaces calculated using the B3LYP functional (see text for explanation of energy scale)

other hand, the BSSE correction reduces the surface energies by about 0.1 J/m², making them closer to the PW result [790]. However, it should be noted that the difference between (110) and (100) surface energies is smaller using the B3LYP functional.

In Table 11.16, we compare the bandwidths for the different surface models; the calculated Fermi energy is also included.

Table 11.16 shows that a clean (110) surface has a wider VB and a narrower BG than a clean (100) surface. This fact can be attributed to the difference in distribution of the electronic states corresponding to bridging oxygens on these two surfaces. It is known that just the bridging oxygens primarily contribute to the density of electronic states at the top of the VB. The LCAO calculations confirm this conclusion. We compare the obtained total DOS of the valence band for bulk, (110), and (100) surfaces in Fig. 11.16.

Here, and in all figures below, the zero energy is taken at the Fermi level of the bulk crystal, and all curves were shifted in such a way that the centers of O 1s bands coincide. All DOS values have been calculated per Sn₂O₄ formula unit in the solid

Table 11.17 Vertical displacements (Å) and atomic charges^a (*e*) on the SnO₂ (110) surface (5-Sn₂O₄-layer slab) results using LCAO DFT (B3LYP calculations; AH—associatively hydroxylated, DH—dissociatively hydroxylated) [799]

Atom ^b	Bare surface		AH surface		DH surface	
	<i>z</i> -shift ^c	charge	<i>z</i> -shift	charge	<i>z</i> -shift	charge
Sn _{6f} , six-fold surface tin	0.21 (0.22)	1.91	0.10	1.97	−0.05	1.96
Sn _{5f} , five-fold surface tin	−0.12 (−0.11)	1.76	−0.06	2.00	0.04	1.99
O _{br} , bridging oxygen	0.05 (0.09)	−0.91	0.05	−1.01	0.02	−0.79
O _s , three-fold surface oxygen	0.14 (0.18)	−0.93	0.04	−1.02	−0.01	−1.03
O _{uf} , subbridging oxygen	0.04 (0.07)	−1.03	0.03	−1.03	−0.02	−1.04
O _{uf} , oxygen underneath Sn _{5f}	−0.04 (−0.04)	−0.93	−0.01	−1.04	0.02	−1.03
O _{term} , oxygen in terminal hydroxyl or water oxygen	—	—	—	−0.66	—	−0.84
H _{term} , hydrogen at O _{term} or corresponding water hydrogen	—	—	—	0.35	—	0.34
H _{br} , hydrogen at O _{br} or corresponding water hydrogen	—	—	—	0.39	—	0.38

^a Charges in the bulk SnO₂: $q(\text{Sn}) = 2.12$, $q(\text{O}) = -1.06$; charges in the isolated water molecule: $q(\text{O}) = -0.62$, $q(\text{H}) = 0.31$.

^b For atom indexing, see text.

^c DFT result of [790] is given in parentheses.

phase to permit comparison on an equal scale. It is clearly seen in Fig. 11.16 that the new O_{br} subband appears in the surface systems at the top of the bulk VB.

In the case of a (110) surface, the broadening of the DOS distribution toward the BG is wider, and the separation of the O_{br} subband from the bulk VB is more prominent than those in the case of a (100) surface. This fact indicates [767] that the basicity of O_{br} is larger on a (110) surface than on a (100) surface.

Vertical displacements of the surface atoms relative to their positions in the bulk structure are reported in Tables 11.17 and 11.18.

As expected, the top-surface atoms have the largest displacements. However, there is a qualitative difference between the two surfaces under consideration. Namely, in the case of a (110) surface, the shifts of Sn_{5f} (inward) and Sn_{6f} together with O_s (upward) are the most noticeable, while in the case of a (100) surface, only the bridging oxygen has a marked positive displacement. In spite of the different calculation methods used, the agreement of these LCAO values with the PW data from [790] is excellent.

The Mulliken population analysis has been applied for the calculation of the atomic charges that are also included in Tables 11.17 and 11.18. The noticeable

Table 11.18 Vertical displacements ($\text{\AA}$) and atomic charges (e) on the SnO_2 (100) surface (5- Sn_2O_4 -layer slab) results using LCAO DFT (B3LYP calculations)^a, [799]

Atom	Bare surface		AH surface		DH surface	
	z -shift ^c	charge	z -shift	charge	z -shift	charge
Sn_{5f} , surface five-fold tin	0.03 (0.05)	1.67	0.02	1.95	−0.01	1.97
Sn_{6f} , surface six-fold tin	0.00	2.07	0.00	2.10	−0.01	2.11
O_{br} , bridging oxygen	0.13 (0.18)	−0.83	0.05	−1.03	0.00	−0.81
O_s , three-fold surface oxygen	0.07 (0.09)	−0.94	0.04	−1.02	−0.02	−1.05
O_{u5f} , oxygen underneath Sn_{5f}	−0.02	−0.95	−0.01	−1.04	0.01	−1.03
O_{u6f} , oxygen underneath Sn_{6f}	0.00	−1.05	0.00	−1.06	−0.01	−1.06
O_{term} , oxygen in terminal hydroxyl or water oxygen	−	−	−	−0.65	−	−0.85
H_{term} , hydrogen at O_{term} or corresponding water hydrogen	−	−	−	0.35	−	0.32
H_{br} , hydrogen at O_{br} or corresponding water hydrogen	−	−	−	0.40	−	0.40

^aSee footnotes to Table 11.17.

reduction of the absolute charges for the top-surface atoms is seen. This effect is relatively larger for a (100) surface than for a (110) surface. Thus, the charge of Sn_{5f} decreases by 0.36 on a (110) surface, while on a (100) surface, it decreases by 0.45 relative to the tin charge in the bulk crystal.

No such significant charge reduction was found in the case of rutile TiO_2 [773] for the surface Ti atoms. The O_{br} charge on a (110) surface is more negative than that on a (100) surface (−0.91 vs. −0.83). This correlates with the conclusion about the larger basicity of the bridging oxygen on the (110) surface.

The results of LCAO calculations of the bare-surface slabs validate the admitted approach (including single-slab model, LCAO basis, and BSSE correction) and indicate that the use of hybrid functionals to describe SnO_2 surfaces provides more reasonable results.

PW-DFT calculations [794] predicted a significant difference in the structure of adsorbed H_2O on (110) TiO_2 (rutile) and SnO_2 surfaces, where the dissociative adsorption was favored on SnO_2 versus associative adsorption on TiO_2 . The difference in H_2O behavior on the surface was attributed [794] to the larger 2D unit-cell parameters of SnO_2 compared to those of TiO_2 ($a = 3.186 \text{ \AA}$, $b = 6.699 \text{ \AA}$ vs. $a = 2.959 \text{ \AA}$, $b = 6.497 \text{ \AA}$, respectively). The larger unit-cell dimensions caused H-bonding among the adsorbed H_2O molecules on the surface to be less energetically important on SnO_2 than on TiO_2 .

It was pointed out in [767] that molecular adsorption on an oxide surface can be understood as an acid–base process. From this point of view, the more covalent character of the Sn–O bonds compared to the corresponding Ti–O bonds might be the second factor that enforces the dissociation of water on the SnO_2 surface. In

fact, the electronegativity of tin (1.8) is markedly greater than the electronegativity of titanium (1.4). The significant reduction of the top-surface Sn_{5f} charges (see Tables 11.17 and 11.18) correlates with the higher electronegativity of tin. As a result, the hydrated Sn_{5f} ion perhaps is a stronger Brønsted acid than the hydrated Ti_{5f} ion on the rutile surfaces. The water hydrolysis can obviously be promoted further by the larger basicity of the bridging oxygens (see discussion below).

To check the validity of the computational scheme used for describing the hydrogen bonds, a preliminary calculation of the water–water interactions has been made [799]. Full geometry optimization has been made for the isolated water dimer starting with the well-known most favorable relative orientation of the water molecules. The values of 30 kJ/mol using PBE and 26 kJ/mol using B3LYP for the H-bond energy (without zero-point correction and BSSE correction) have been obtained. This is not bad compared to the corresponding MP2 value, 25 kJ/mol. The optimal geometry is also very close to the MP2 result: the O–O distance is 2.86 Å, 2.88 Å, and 2.91 Å for PBE, B3LYP, and MP2 calculations, respectively. On the other hand, this example shows that the energy difference of the order of 5 kJ/mol per H-bond is within the error bounds of the usual DFT calculations. It also gives evidence that the B3LYP functional can produce more correct values for H-bonded systems.

A single-slab LCAO approach was firstly used in [799] for modeling the water adsorption on SnO_2 surfaces. A doubled (in the x -direction) 2D unit cell was used to model the water adsorption on both surfaces. The Monkhorst–Pack 3×3 and 3×4 sets of special k -points were taken for the Brillouin-zone sampling in (110) and (100) slabs, respectively. Up to fifteen atomic planes were included in both types of SnO_2 slabs for the adsorption-energy calculation. Two water molecules were placed on each side of the slab to simulate the full-monolayer coverage. Inversion symmetry was imposed on all systems containing water molecules to ensure the equivalence of both slab sides. The optimization of all atomic positions in the slabs has been made. The contribution of BSSE to the calculated adsorption energies has been estimated using the PBE functional. As in the case of the surface-energy calculation, the ghost atoms have been added to represent the water molecules above the optimized slabs, and the total energy was recalculated. The energy of the isolated water molecule has also been recalculated with the 10–15 ghost atoms originated from the corresponding SnO_2 surfaces. The resulting BSSE is approximately independent of the surface kind and reaches 18 kJ/mol of adsorbed water (see Table 11.19).

Although this is a noticeable contribution, it decreases all calculated adsorption energies by almost the same value and does not influence the relative stability of associative and dissociative adsorption forms. The obtained adsorption energies for the (110) surface (Table 11.19) satisfactorily agree with the former periodic-slab PW–DFT calculations [793, 794].

In simulations [799], the water molecules initially were placed above the fivefold tin. During the optimization, both (on each side) water molecules spontaneously dissociated in the case of PBE calculations, whereas a stable associative structure has been obtained in the case of the B3LYP functional (Fig. 11.17a).

Table 11.19 Ab initio adsorption energies per water molecule for H₂O monolayer on SnO₂ surfaces (N/M —Number of atomic planes/Sn₂O₄ layers) [799]

Surface	Cell	k -set	N/M	Method	Adsorption energy (kJ/mol)	
					associative	dissociative
110	2×1	3×3	15/5	LCAO DFT (PBE)	<i>unstable</i>	−179.7 (−162) ^a
				LCAO DFT (B3LYP)	−143.2	−176.6
				PW DFT (PW91)[793]	<i>unstable</i>	−165.0
				PW DFT (PW91)[794]	<i>unstable</i>	−170.8
100	2×1	3×4	15/2.5	LCAO DFT (PBE)	−130.2 (−112) ^a	−147.0 (−129) ^a
				LCAO DFT (B3LYP)	−116.86	−145.0

^a BSSE-corrected values are given in parentheses for LCAO DFT (PBE) calculations

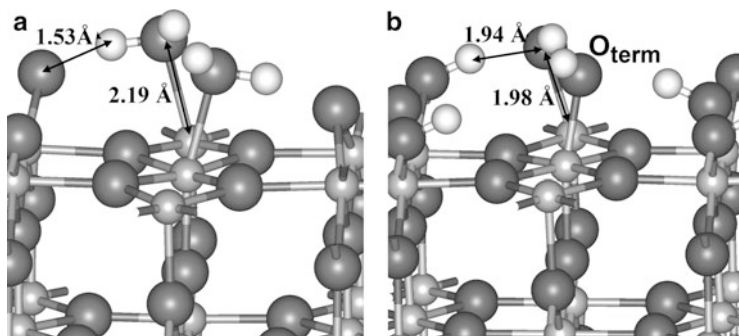


Fig. 11.17 Optimized monolayer structure for the water molecules adsorbed on a (110) SnO₂ surface obtained using the B3LYP functional [799]: (a) stable structure for molecular adsorption and (b) stable structure for dissociative adsorption. Large dark-gray balls are O atoms; light-gray balls are Sn atoms; small white balls are H atoms

Hence, in contrast to previous DFT calculations, the hybrid HF–DFT functional leads to stable molecular adsorption on this surface. Starting with the broken water molecules, a stable dissociated structure has been obtained where hydroxyls were attached to fivefold tin and protons were bonded to the bridging oxygens (Fig. 11.17b). The energy of the hydrolyzed structure is lower by about 35 kJ/mol than the energy of the molecular structure (see Table 11.19). It is difficult to compare directly these adsorption energies of water on SnO₂ with those on TiO₂ [773] due to the different methods used; however, the adsorption on a (110) surface of cassiterite seems to be more exothermic by approximately 30 kJ/mol than the adsorption on a (110) surface of TiO₂. This conclusion is in accordance with the DFT result of [792],

where it is found that the dissociative configuration gives an adsorption energy of 134 kJ/mol for $\text{SnO}_2(110)$ and 104 kJ/mol for $\text{TiO}_2(110)$. In [792], it has been roughly estimated that the experimental adsorption energy on $\text{SnO}_2(110)$ should be about 110 kJ/mol. The data in Table 11.19 show that most of the theoretical values are 50% larger than the proposed estimation.

Both resulting geometries are stabilized by the H-bonds between water hydrogen and bridging oxygen in the associative case (Fig. 11.17a) and bridging hydrogen and oxygen of the terminal hydroxyl in the dissociative case (Fig. 11.17b). It should be noted that the PBE functional produces shorter hydrogen bonds than the B3LYP functional. In contrast to the (110) TiO_2 surface, there is no sufficiently strong interaction between the neighboring water molecules on the (110) SnO_2 surface. The distance Ow–Ow between the water oxygens is 3.1 Å and 3.4 Å on TiO_2 and on $\text{SnO}_2(110)$ surfaces, respectively. This is in accordance with the results of Lindan [794], who pointed out the role of intermolecular interactions in the stabilizing of the molecular adsorption on the (110) TiO_2 surface. On the other hand, the H-bond between water hydrogen and bridging oxygen proves to be very short, 1.53 Å, indicating the large basicity of O_{br} . Moreover, H-bonds, which could be hypothetically obtained with the PBE functional for molecular adsorption on a (110) surface, should be even shorter than those using the B3LYP functional, as occurs in all other cases with the real H-bonds. This can be the main reason why the molecular adsorption becomes unstable using the PBE variant of DFT. Also, this example shows that particular approximations influence the details of the calculated potential energy surface for the water–oxide interactions.

Taking into account the fact that the B3LYP approximation gives the better values of energy and bond distances for the H-bonded systems, it can be supposed that hybrid HF–DFT functionals can produce the more correct data for the water adsorption as well. This could be important not only in the case of SnO_2 but also for other materials: applying the hybrid functionals may lead to the greater stability of molecular forms adsorbed on the oxide surfaces than predicted by plain DFT techniques.

Whereas many groups have studied the water adsorption on TiO_2 surfaces, there have been few experimental water-adsorption studies for SnO_2 . In [805], thermal desorption spectroscopy and ultraviolet photoemission spectroscopy have been used to investigate perfect and defective surfaces of SnO_2 . In this study, it was suggested that the amount of dissociation was about 10–15% on the stoichiometric (110) surface and the dissociation increased to 35% on the defective surface. Although additional experimental and theoretical work may be needed to confirm these conclusions, these data at least show that the molecular form of water can be stable on the cassiterite (110) surface, which is in accordance with B3LYP results under consideration.

The DOS for both types of water adsorption on a (110) surface are displayed in Fig. 11.18.

In the molecular adsorption case, depicted in Fig. 11.18a, the O_{br} subband tightly adjoins the bulk VB states, and a new O_{w} subband (corresponding to the water electronic states) was formed at the bottom of the VB. For comparison, the clear

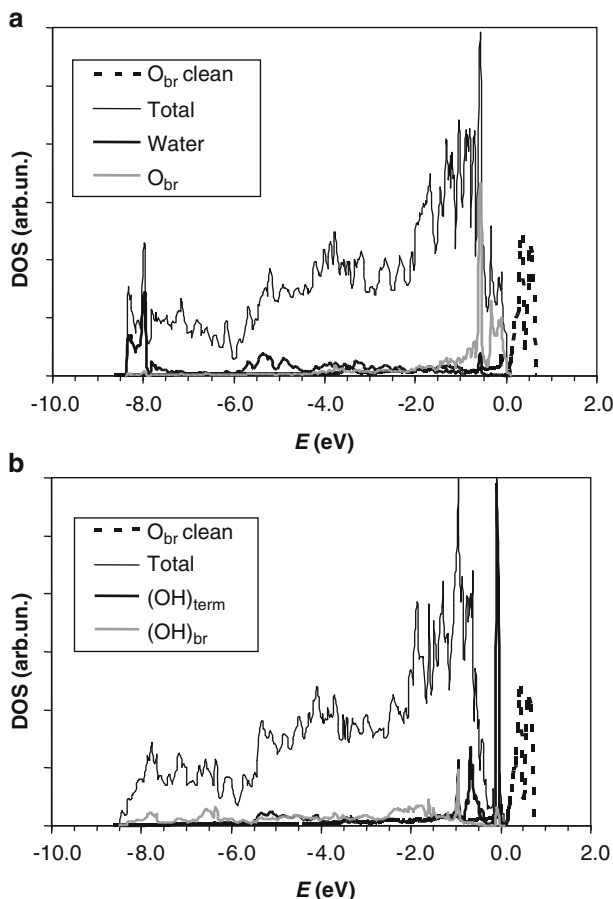


Fig. 11.18 Total and O-projected valence-band DOS in the hydroxylated (110) SnO_2 surface systems (see text for explanation of energy scale) [799]. **(a)** Molecular adsorption: total DOS (*fine line*), projection onto the water states (*bold dark line*), projection onto the O_{br} states (*bold gray line*); **(b)** dissociative adsorption: total DOS (*fine line*), projection onto the $(OH)_{term}$ states (*bold dark line*), projection onto the $(OH)_b$ states (*bold gray line*). The projection onto the O_{br} states in the clean (110) surface is shown by a dotted line

surface DOS projected to bridging oxygen states is also plotted in Fig. 11.18. In the dissociative case, Fig. 11.18b, the O_{br} subband almost completely disappeared and three new peaks originated from electronic states of the terminal hydroxyl group. One of these peaks is very sharp and is prominently separated from the top of the VB. As in the case of the (110) surface, two different initial states were chosen for the (100) surface. In the first, the water molecules were placed near the fivefold tin. The optimization did not change considerably the positions of water molecules using both PBE and B3LYP functionals (Fig. 11.19a).

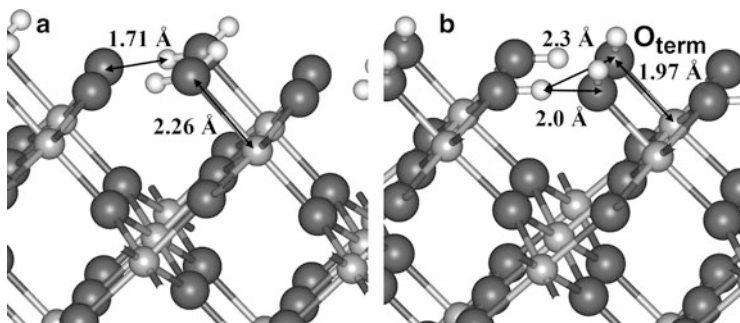


Fig. 11.19 Optimized monolayer structure for the water molecules adsorbed on a (100) SnO_2 surface obtained using the B3LYP functional [799]: (a) stable structure for molecular adsorption; (b) stable structure for dissociative adsorption. Large dark-gray balls are O atoms, light-gray balls are Sn atoms; small white balls are H atoms

Thus, the molecular form of adsorption is obviously stable on the (100) surface. The relative positions of fivefold tin and bridging oxygen favor the formation of H-bonds between the water hydrogen and bridging surface oxygen (Fig. 11.19a), although these bonds are not so short as in the (110) case. A stable structure for the dissociative adsorption (Fig. 11.19b) was obtained from another initial state with the broken water molecules. There are no straight-line H-bonds in this structure. Nevertheless, as in the case of the (110) surface, the dissociative adsorption is more favorable (by about 30 kJ/mol) for the (100) SnO_2 surface. The absolute value of the adsorption energy on a (100) surface is lower than that on a (110) surface. This is in accordance with the PW-DFT investigation of Bandura et al. [774].

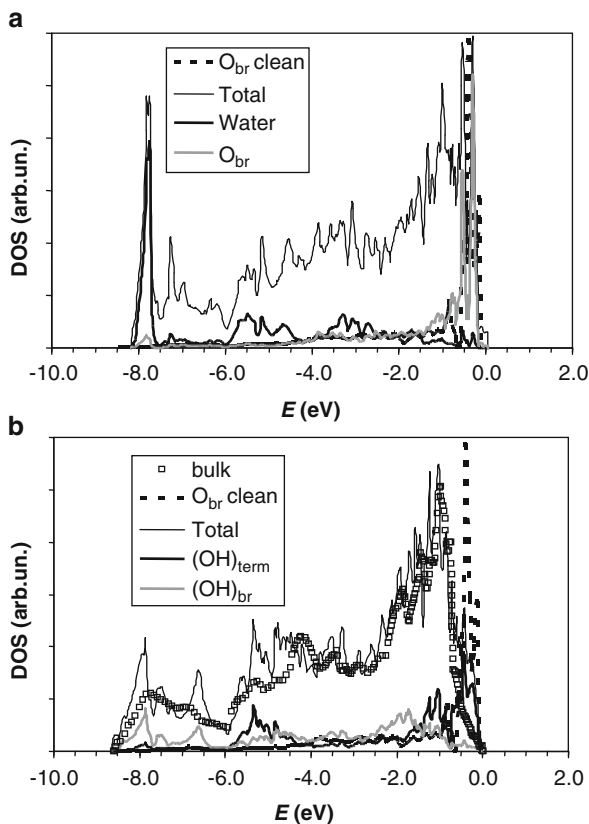
As may be expected, the atomic displacements for the hydroxylated surfaces are much smaller (especially for the dissociative adsorption) than those in the case of the bare surfaces (Tables 11.17 and 11.18), due to saturation of the vacant coordination places for the surface tin up to the total coordination number 6. Data in Tables 11.17 and 11.18 show that oxygen charges in the hydroxyl groups are noticeably less negative than charges on the other surface oxygens. The hydrogen charges were arranged in the order $q(\text{H}_{\text{br}}) > q(\text{H}_{\text{term}}) > q(\text{H}_{\text{H}_2\text{O}})$, which correlates with the relative acidity of the corresponding O-H bonds [806].

Figure 11.20 reports the DOS distributions for hydroxylated (100) surfaces. The DOS for the associative adsorption (Fig. 11.20a) differs from that for the clean (100) surface mainly by the presence of the O_w subband at the bottom of the VB.

The difference between the DOS for the slab dissociatively adsorbing water (Fig. 11.20b) and the DOS for the clean (100) surface is less significant than that in the (110) case. The terminal OH states also contribute to the top of the VB, but corresponding peaks are not as sharp as for the hydroxylated (110) surface. Except for the narrow zone at the top of the VB, the total DOS in the last case resembles the total DOS for the bulk crystal, which is also plotted in Fig. 11.20b for comparison.

Comparing the results for the clean and hydroxylated surfaces, one can conclude that a (110) surface exhibits stronger hydrophilic properties than a (100) surface due

Fig. 11.20 Total and O-projected valence-band DOS in the hydroxylated (100) SnO_2 surface systems. (a) Molecular adsorption; (b) dissociative adsorption. (The sense of line types and energy scale are the same as in Fig. 11.19.) The projection onto the O_{br} states for the clean (100) surface is shown by the dotted lines, and the total bulk DOS is shown in (b) by open circles



both to the more favorable geometrical structure and the more basic nature of the bridging oxygen.

The discussion above demonstrates that use of the hybrid HF–DFT approach allowed new results for the clean and hydroxylated oxide surfaces compared with plain DFT techniques to be obtained. The comparison of plain DFT functionals with the HF–DFT B3LYP hybrid functional shows interesting differences, which could be important not only in the case of SnO_2 but also for other materials: in contrast to DFT plane-wave calculations (spontaneous dissociation), an associated adsorption of the water molecules becomes possible not only in the case of the (100) surface but also at the most stable (110) surface judging by the hybrid functional. This fact is probably due to the shortening of the H-bonds by the plain DFT methods.

LCAO HF–DFT investigation, as well as previous plane-wave calculations, shows that water dissociation on SnO_2 surfaces is more favorable than on the similar TiO_2 surfaces. Not only may the geometrical factors favor the hydrolysis of water on cassiterite surfaces but also the more covalent nature of Sn–O bonds and the larger basicity of bridging oxygens in SnO_2 comparably to TiO_2 .

One can conclude that the arrangement of H-bonds between the hydroxyl hydrogens and surface oxygens, as well as between the water molecules themselves, plays an important role in stabilizing the water adsorption on the metal-oxide surfaces. Thus, one of the reasons why the absolute value of adsorption energy on a (100) surface is lower than that on a (110) surface is the relative positions of oxygen and tin atoms being less profitable for the H-bond formation.

The general agreement between the results of calculations using the different bases (LCAO and PW) or the different slab models (2D and 3D) justifies the validity of the various *ab initio* methods to study the molecular adsorption on the crystalline surfaces. However, the BSSE correction may be needed to obtain more precise absolute adsorption energies within the LCAO calculations.

In the next section we consider the surface modeling in cubic perovskites.

11.3 Slab Models of SrTiO₃, SrZrO₃, and LaMnO₃ Surfaces

11.3.1 Hybrid HF–DFT Comparative Study of SrZrO₃ and SrTiO₃ (001) Surface Properties

A variety of practical applications of perovskite systems ABO₃ (the piezoelectrical and electro-optical devices, fuel cells, microelectrodes) have stimulated experimental and theoretical investigations of their surfaces.

Neither experimental nor theoretical investigations of the (001) surface structure of SrZrO₃ are known. However, a large number of experimental studies of SrTiO₃ (001) surfaces have been reported, see [807,808] and references therein. In some of these investigations, the reconstructed surfaces have been observed. A reconstruction of the SrTiO₃ surface mostly relates to surface defects, *for example*, oxygen vacancies that can be created by annealing in O₂ atmosphere at high temperature [809]. At the same time, the relaxation of a perfect titanate surface (no oxygen vacancies) has been experimentally observed and investigated [810]. This confirms the fact that perovskite surfaces with regular stoichiometry can be stable in some conditions. The displacements of atoms for the surface relaxation have been found in [810] by medium-energy ion-scattering (MEIS) method. Charlton et al. [811] have used room-temperature surface X-ray diffraction (SXRD) to investigate the 300 K structure of SrTiO₃(001) with 78% terminated TiO₂ and 22% terminated SrO. For the TiO₂ surface, there is good agreement with MEIS data in the position of the top-layer Ti, with both techniques pointing to an essentially bulk-terminated position. The data in [811] indicated that a lateral ferroelectric distortion is absent at 300 K on both terminations, consistent with some theoretical calculations [812]. However, a reflection high-energy electron diffraction (RHEED) study of the SrTiO₃ (001) surface structure in a temperature region from 300 down to 5 K [813] gave evidence for a surface phase transition of a soft-mode type, promoted by the surface symmetry.

The properties of the SrTiO_3 (001) surface have been examined in many quantum-mechanical studies [807, 812, 814–816, 819, 820]. Calculations of (001) surfaces of BaTiO_3 , PbTiO_3 [758, 821–824], and defective (001) and (110) SrTiO_3 surfaces [825, 826] have also been made. A large number of cited calculations of surface properties of the strontium titanate are based on density-functional theory (DFT) and plane-wave basis (PW) set. In DFT LDA simulations [812] of the surface relaxation, it has been found that relaxations account for 0.18 eV of the surface energy per surface unit cell, compiling around 15% of the total surface energy (1.36 J/m²). Examining slabs with different surface terminations, the authors conclude that the bandgap (BG) for the SrO surface almost does not change with respect to the bulk value, and no ingap state occurs. For the TiO_2 surface, there is a substantial reduction of the BG. However, there are also no deep-gap surface states, in accord with experimental reports. It should be noted that the LDA approach utilized in [812] (as well as the generalized gradient approximation, GGA) tends to underestimate the BG and leads to a substantial discrepancy between calculated (1.85 eV) and experimental (3.30 eV) BG for the bulk SrTiO_3 .

In [816, 819], the results of GGA calculations for SrTiO_3 surface systems are reported. In general, the data obtained in these studies do not differ considerably from LDA results except for the values reported in [819] for atomic displacements that seem to be on the order of a half of the values reported by all other DFT studies and may be attributed to some systematic error. Again, no midgap surface state for either TiO_2 - or SrO-terminated surfaces was found in the band structure [819]. However, a clear small peak appears below the energy gap in the electronic density of states (DOS) of the TiO_2 -terminated surface, which has a tendency to move into the midgap. In [816] the electron redistribution in the surface layers has been analyzed using charge-density decomposition based on the Bader criteria [827]. The authors concluded that relatively strong hybridization between the Ti and O atoms leads to a noticeable charge transfer in the SrTiO_3 surface systems. This enhanced charge transfer correlates with the strength of the surface relaxation.

In [807, 814, 815] HF and DFT LCAO calculations of (001) SrTiO_3 surface employing a number of different exchange-correlation functionals have been performed. Prior to investigation of the surface properties, these authors tested the different quantum-mechanical methods on some bulk characteristics such as the lattice constant, bulk modulus, and BG. They obtained the best agreement between theoretical and experimental data for the hybrid HF–DFT B3PW method. The surface structure, surface energies, and electronic properties of the SrTiO_3 (001) surface has been calculated by different HF and DFT LCAO methods. It was concluded that it is very difficult to choose a method reproducing all properties equally well, but hybrid HF–DFT techniques B3PW and B3LYP turned out to be the most reasonable.

In [828] the comparison has been made between the calculated relaxed structures of the SrTiO_3 surface obtained in various DFT–PW studies and the data of several experimental investigations. Good agreement was found between the most theoretical studies, whereas the accordance of theoretical data with the available experimental results proved to be low. This fact can be explained by the poor

agreement between the different experimental studies themselves [812, 814]. It was suggested in [811] that a possible reason for this discrepancy is the influence of soft vibrational modes, which are thought [782] to give rise to a 0.2 Å-disagreement between 0 K theory and 300 K experiment for TiO₂ (110). Whatever the origin of the discrepancy, it presumably affects the TiO₂-terminated surface and the second-layer atoms on both surface types of SrTiO₃ crystal.

We discuss here in more detail the results of a hybrid HF-DFT LCAO comparative study of cubic SrZrO₃ and SrTiO₃ (001) surface properties in the single-slab model [808]. As known from [807], the consideration of systems with 7–8 atomic layers is sufficient to reproduce the essential surface properties of cubic perovskites. Three different slab models have been used in [808]. The first (I) and the second (II) ones consist of 7 crystalline planes (either SrO- or MO₂-terminated, respectively) being symmetrical with respect to the central mirror plane but nonstoichiometric (see Fig. 11.4). The central layer is composed of MO₂ (M = Ti, Zr) units in model I and SrO units in model II. Both models I and II have been applied for studying the surface properties of titanates by *ab initio* calculations [815]. The asymmetric model III is stoichiometric and includes 4 SrO and 4 MO₂ atomic planes. Accordingly, it is terminated by a SrO plane on one side and by a MO₂ plane on the other side, and there is no central atomic layer. Model III has been included in the simulation to investigate the influence of the stoichiometry violation in the symmetrical models I and II on the calculated surface properties. For all slabs a 1 × 1 surface unit cell has been taken. For the 2D translations in slabs the experimental bulk lattice constants of SrZrO₃ (4.154 Å) and SrTiO₃ (3.900 Å) were used that do not differ significantly from DFT B3PW LCAO theoretical values (4.165 Å and 3.910 Å respectively).

In Table 11.20 are presented the results obtained for charge distribution and atomic relaxations for models I and II (Mulliken atomic charges and vertical atomic displacements are given). The displacements in the normal to the surface direction are given with respect to atomic positions in the unrelaxed bulk structure. The negative displacements correspond to the relaxation inward, toward the bulk, while the positive ones relax outward, *that is*, to the vacuum side. It should be noted that the positions of atoms in the central plane exactly fit the corresponding bulk sites and cannot relax due to the imposed mirror symmetry. There are no such restrictions for model III. However, the absolute atomic displacements cannot be calculated unambiguously in this case due to uncertainty in the zero-level choice when the relaxed and unrelaxed structures are superimposed. This problem may be overcome by fixing the positions of the two middle layers at the bulk geometry. Model III does not satisfy this condition, so the corresponding absolute atomic displacements have not been calculated in model III.

The obtained displacement d values for the SrTiO₃ practically coincide with the shifts from calculations [814] where almost the same LCAO procedure has been used. Calculated vertical shifts for the upper Sr atoms are noticeably greater than the shifts of other atoms in both models I and II, though they are negative in the first and positive in the second case. Also, for SrZrO₃, they are larger than for SrTiO₃. Displacements of other atoms are very similar on SrZrO₃ and SrTiO₃ surfaces, except the inward shift of the top oxygen atom on the ZrO₂ surface

Table 11.20 Mulliken charges¹ q ($|e|$) and vertical atomic displacements d (Å) for the SrO- and TiO₂-terminated slabs models (I and II, respectively)

Model	Layer	SrZrO ₃			SrTiO ₃			d_{calc} ²	d_{exper} ³
		Ion	q	d	Ion	q	d		
I	1	Sr	1.86	−0.304	Sr	1.85	−0.185	−0.220	−0.25 ± 0.07
		O	−1.50	0.035	O	−1.52	0.036	0.004	−0.3 ± 0.4
	2	Zr	2.17	0.083	Ti	2.36	0.075	0.046	−0.24 ± 0.07
		O ₂	−1.38	0.027	O ₂	−1.45	0.040	0.000	−0.4 ± 0.7
	3	Sr	1.88	−0.058	Sr	1.87	−0.031	−0.046	0.02 ± 0.04
		O	−1.36	0.006	O	−1.43	0.009	−0.004	0.1 ± 0.2
	4	Zr	2.13	–	Ti	2.36	–	–	
		O ₂	−1.35	–	O ₂	−1.42	–	–	
II	1	Zr	2.16	−0.092	Ti	2.29	−0.084	−0.131	0.00 ± 0.03
		O ₂	−1.26	−0.097	O ₂	−1.30	−0.005	−0.062	−0.5 ± 0.3
	2	Sr	1.86	0.159	Sr	1.85	0.140	0.097	−0.01 ± 0.01
		O	−1.27	0.025	O	−1.36	0.020	−0.019	0.2 ± 0.1
	3	Zr	2.12	−0.014	Ti	2.35	−0.010	−0.027	
		O ₂	−1.31	−0.008	O ₂	−1.38	0.002	−0.019	
	4	Sr	1.87	–	Sr	1.87	–	–	
		O	−1.33	–	O	−1.40	–	–	

¹ Bulk charges: SrZrO₃: $q(\text{Sr}) = 1.88$, $q(\text{Zr}) = 2.12$, $q(\text{O}) = -1.33$; SrTiO₃: $q(\text{Sr}) = 1.87$, $q(\text{Ti}) = 2.53$, $q(\text{O}) = -1.47$.

² Experimental data [811] for SrTiO₃ at 300 K.

³ Results of DFT–PW calculations [812] using the optimized lattice constant $a = 3.86$ Å.

that is much greater than the shift of the corresponding oxygen atom on TiO₂ surface. The X-ray diffraction data [811] for SrTiO₃ (001) surface are presented in the last column of Table 11.20. Note that the experimental values correspond to 300 K, whereas the theoretical values correspond formally to 0 K. As well as in other *ab initio* investigations, the satisfactory agreement between the theory and experiment was found only for the displacements of the top Sr atoms in model I. The comparison of calculated and measured displacements for the deeper atoms in SrTiO₃ slabs is difficult as the experimental data reveals large errors. Furthermore, in these slab simulations, as in most other studies, the cubic bulk unit cell is used to generate the surface unit cell and the corresponding symmetry (in the surface plane) is kept fixed, whereas the unit cell must be doubled and symmetry should be lowered to tetrahedral for reproducing of the ferroelectric distortions. Most certainly, the surface phase transition can also take place in the case of zirconate due to the existence of the lower-symmetry orthorhombic modification at room temperature. Table 11.20 also presents the results of a previous LDA PW simulation [812] for SrTiO₃. LCAO displacements satisfactorily correlate with the data of PW calculations.

The Mulliken atomic charges are also given in Table 11.20. These quantities can be used for analysis of the electron redistribution in the surface layers, which may

Table 11.21 The calculated surface energies E_s (J/m²) and bandgaps BG (eV)

	Relaxed				Unrelaxed		
Quantity	I	II	(I+II)/2	III	(I+II)/2	III	Bulk
SrZrO ₃							
E_s	1.01	1.26	1.14	1.13	1.41	1.42	
BG	4.84	4.61	–	4.56	–	3.94	5.02 ¹
SrTiO ₃							
E_s	1.20	1.29	1.25 (1.36) ²	1.24	1.46 (1.55) ²	1.46	
BG	3.68 (1.86) ²	2.76 (1.13) ²	–	2.48	–	2.63	3.65 ¹ (1.85) ²

¹Experimental BG in bulk crystals: 5.9 eV for SrZrO₃ [818] and 3.3 eV for SrTiO₃ [817].

²The results of DFT–PW calculations [812] are given for comparison in parentheses.

be important for adsorption of another species on the surface. Table 11.20 clearly shows that the Sr atomic charge is close to the bulk one and exhibits insensitivity to the kind of M atom, type of termination, and number of layers. On the contrary, calculated Ti and Zr charges give evidence of considerable covalency of M–O bonds in both crystals. It can also be seen that deviations of the surface oxygen charges from their bulk values are relatively large and exhibit the opposite sign for the two types of surface termination. The calculated Mulliken charges are very similar to the charges obtained in [816] via the Bader density decomposition.

When using models I and II, the surface energy E_s can be determined as a sum of two parts, $E_s = E^{\text{unrel}} + E^{\text{rel}}(T)$. The first term E^{unrel} is equal to one-half of the energy for crystal cleavage into SrO- and MO₂-terminated slabs. It can be written as

$$E^{\text{unrel}} = \frac{1}{4S} [E_{\text{slab}}^{\text{unrel}}(\text{SrO}) + E_{\text{slab}}^{\text{unrel}}(\text{MO}_2) - 7E_{\text{bulk}}] \quad (11.10)$$

where $E_{\text{slab}}^{\text{unrel}}(\text{SrO})$ and $E_{\text{slab}}^{\text{unrel}}(\text{MO}_2)$ are the energies for unrelaxed SrO- and MO₂-terminated slabs, E_{bulk} is a bulk energy per primitive cell, and S is the area of the 2D cell. The second term is the relaxation energy for SrO- or MO₂-terminated slabs and is computed as a difference between the relaxed and unrelaxed slab energies:

$$E^{\text{rel}} = \frac{1}{2S} [E_{\text{slab}}^{\text{rel}}(T) - E_{\text{slab}}^{\text{unrel}}(T)] \quad (11.11)$$

where $T = \text{SrO}$ or MO_2 .

The surface energy of model III (stoichiometric slab) equals the difference between the energy of the slab and the quadruple energy of bulk primitive cell divided by $2S$. The results for surface energy are summarized in Table 11.21.

For both crystals, E_s for SrO termination is slightly less than that for MO₂ termination. It is important that the surface energies averaged over models I and II

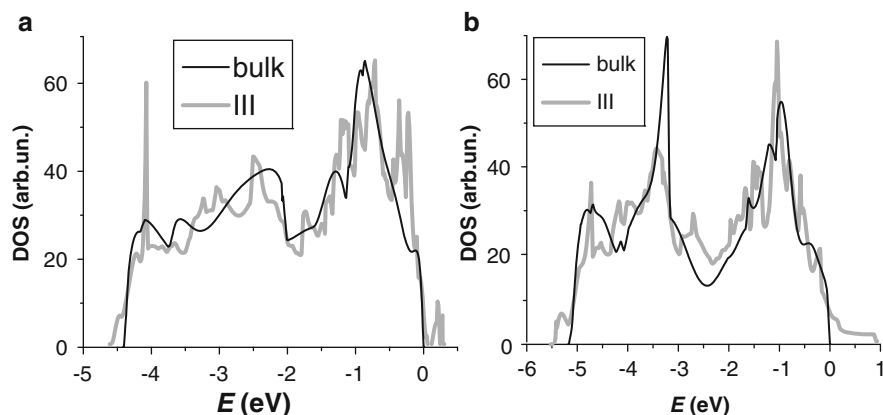


Fig. 11.21 Oxygen-projected VB DOS for bulk crystal and for surface model III (a—SrZrO₃; b—SrTiO₃)

are very close to E_s for model III (this is valid both for relaxed and unrelaxed systems). The obtained values show that the surface energy of SrZrO₃ is smaller than the surface energy of SrTiO₃ crystal. The calculated value for the surface energy of SrTiO₃ (1.24–1.25 J/m², see Table 11.21) agrees satisfactorily with the value calculated in [812] using the DFT–PW framework (1.36 J/m²).

In Table 11.21 the calculated bandgaps (BG) for slabs are compared. It is clearly seen that in all cases the BG for SrZrO₃ systems is wider. This agrees with the larger ionicity of SrZrO₃ in comparison with SrTiO₃. One can notice that in the case of SrTiO₃, the BG for model I is markedly greater than that for models II and III. The substantial reduction of BG for the TiO₂ surface relative to the bulk value is due to an extended shoulder in the valence-band electronic DOS (see below). The same picture has been found in DFT–PW calculations [812], in spite of the fact that the LDA gaps are half of others (see Table 11.21).

In all figures below, the zero energy is taken at the Fermi level of the bulk crystal (SrZrO₃ or SrTiO₃), and all curves were shifted so that the centers of O 1s bands coincide. Also, the DOS values have been reduced to one oxygen atom to ensure the same scale for bulk crystal and different slabs.

In Fig. 11.21, the total oxygen DOS for surface model III and bulk crystal is compared. The bulk and slab VB have similar shapes and widths except the small areas at the top and bottom that reflect the surface contributions.

These contributions are resolved in Fig. 11.22 where the DOS projected to the surface oxygens is plotted. Figure 11.22a and b demonstrates that the oxygen DOS distribution for SrO and TiO₂ terminations is qualitatively different, whereas the distinctions between the model types (I and III or II and III) are less significant.

It is clearly seen in Fig. 11.22 that the new O-subbands appear in the slabs at the top of the bulk VB. The corresponding peaks for the oxygen on an SrO-terminated SrZrO₃ surface (in models I and III) are significantly higher than the peaks for

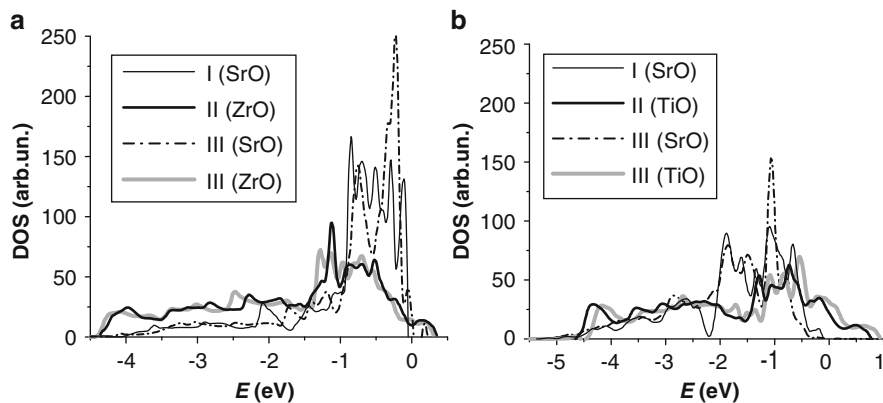


Fig. 11.22 Projected VB DOS for oxygen atom in the first surface layer for all three models (a—SrZrO₃; b—SrTiO₃). For model III, the first oxygen projection corresponds to the SrO side and the second to the MO₂ side

oxygen on ZrO₂-terminated surfaces. Also, the charge of the O atom in the first layer in SrO-terminated slab of a SrZrO₃ crystal is noticeably lower than its bulk value (1.50 vs. 1.33 in Table 11.20). This can be explained by the larger ionicity of the M–O bond in the zirconate than in the titanate.

These features allow one to expect that a (001) SrO-terminated surface can accumulate the excess negative charge in the case of SrZrO₃ crystal and it should be more basic in nature than a SrO-terminated surface of SrTiO₃ crystal. In the case of SrTiO₃ slabs, the corresponding oxygen contribution to SrO surface states is lower, whereas the new surface states originated from the TiO₂ termination form a low but extended shoulder that is alike in models II and III. The indicated shoulder reduces the bulk BG noticeably (see Table 11.21). This means that electronic shells on the TiO₂-terminated SrTiO₃ surface are more polarizable than electronic shells on the other surface types regarded. The similarities of the results obtained for the surface energy and DOS from the surface models I and II on the one hand and from the model III on the other hand confirm the weak interaction between the opposite slab faces if its thickness is sufficiently large, resulting in the mutual independence of two types of termination (SrO and MO₂) in the surface models of perovskites considered.

One can conclude that disagreement between the theory and experiment for the vertical displacements of the SrTiO₃ surface atoms does not depend on the actual (LCAO hybrid HF–DFT or PW–DFT) *ab initio* method used. The dependence on the slab model and thickness may also be excluded from the possible reasons. Most probably, this discrepancy can be explained by the possible surface phase transition or surface reconstruction under the experimental conditions. The *ab initio* calculations using the extended tetragonal surface unit cell can resolve the indicated contradiction. The values obtained show that relaxation of the top-surface atoms is more prominent in the case of SrZrO₃ than in the case of SrTiO₃, and the

corresponding surface energy for zirconate is lower by about 0.1 J/m^2 . This fact may be attributed to the larger ionicity of SrZrO_3 bulk crystal in comparison with SrTiO_3 bulk crystal. The results under consideration give evidence that the SrO surface of a SrZrO_3 crystal is more basic than the SrO surface of a SrTiO_3 crystal. Based on this conclusion, one can suppose, for example, a stronger interaction of oxygen atoms on the SrO surface with the H atoms of the adsorbed water molecules (with possible water ionization) occurs in the case of zirconate than in the case of titanate.

11.3.2 F Center on the SrTiO_3 (001) Surface

In Sect. 10.3.1, we considered the calculations of the oxygen vacancy in a bulk SrTiO_3 crystal (bulk F centers). The atomic and electronic structure of surface F centers is practically unknown.

Only a few theoretical papers deal with the analysis of the F centers on the TiO_2 -terminated SrTiO_3 (001) surface: one of them is based on semiempirical INDO calculations [829] and another one on GGA and LDA+U slab calculations [830]. In both papers, the structure of the F centers was studied for very high defect concentrations as the small 2D supercells were used. It has been demonstrated above in the bulk F center calculations that the results for low defect concentrations might be significantly different from those corresponding to the infinite-dilution limit. Moreover, it is very likely that in the calculations [829], both lattice relaxation and vacancy-formation energies are not converged to the infinite-dilution limit and no surface defect-migration energies were presented.

In [831] the surface F centers on the TiO_2 -terminated unreconstructed (001) SrTiO_3 surface are studied in more detail by the DFT method. A stoichiometric slab containing six atomic TiO_2 and SrO planes (6 bulk unit cells, *i.e.*, 30 atoms) has been chosen as a material model. The surface F center was studied for 2D supercells 2×2 (120 atoms) and 3×3 (270 atoms). The formation energy for relaxed (unrelaxed) surface oxygen vacancies was found to be 6.22 eV (8.86 eV) and 5.94 eV (8.81 eV) for 120-atom and 270-atom supercells, respectively. Again, one must be aware of the fact that the present values might not be completely converged to the infinite-dilution limit. This surface vacancy-formation energy could be compared to the 7.73 eV and 7.17 eV formation energies for the relaxed F centers in the bulk, calculated for the bulk supercells $n\sqrt{2} \times n\sqrt{2} \times n\sqrt{2}$, $n = 2, 3$, with similar interdefect distances along the z-axis. The conclusion could be drawn that the defect-formation energy on the TiO_2 -terminated surface is considerably smaller than in the bulk; it is roughly reduced by 1.5 eV or 20–25%. This is similar to what has been obtained for other oxides, and it is due to the reduced coordination at the surface [833]. The following relaxation of the atoms nearest to the vacancy and in the Ti–O–Ti surface chain is reported in [831]. The Ti and O nearest neighbors of the vacancy are displaced by $7\%a_0$ and $4\%a_0$, respectively (a_0 is the parameter of bulk cubic lattice). The former displacements exceed by a factor of two those in the

bulk and result from the half-coordination sphere left when the surface is formed. Unlike the bulk, where atoms move toward and outward from the O vacancy, on the surface, the direction of atomic displacements is more complicated.

A well-pronounced strong anisotropy in the atomic displacements along the Ti–V_O–Ti axis was clearly observed. Atomic displacements in the smaller supercell show a nonmonotonic decay with the distance from the vacancy that is caused by the interference effects on the border of the nearest supercells and demonstrates that this supercell is not big enough to avoid defect–defect interactions on the surface. The calculated activation energy for defect migration for the two supercells of 120 and 270 atoms is 0.19 and 0.11 eV, respectively. This demonstrates that (a) an increase of the distance between defects reduces the migration energy (due to the reduced repulsion energy between periodically distributed defects) and (b) compared to the bulk migration, the defect-migration energy on the perovskite surface is largely reduced.

This is in line with the calculations of the F-center migration on the MgO surface where the activation energy obtained was also considerably smaller than in the bulk [833]. In addition, high vacancy mobility makes the surface reconstruction easier to see in the experiments. The difference electronic-density map for the surface F center on the $2 \times 2 \times 3$ slab shows that the electronic density around it is more delocalized than that corresponding to the bulk F center. The calculated Bader effective charges of the two nearest Ti atoms give an electronic-density increase of $0.4 e$ per atom, whereas the rest of the missing O charge is spread in the vicinity of the vacancy. Finally, the defect ionization energy of the surface F center is almost half that in the bulk (0.25 eV vs. 0.49 eV). Its dispersion is still not negligible (0.14 eV), being comparable with that for the bulk $2\sqrt{2} \times 2\sqrt{2} \times 2\sqrt{2}$ supercell (0.15 eV). The single bulk F center in SrTiO₃ is a small-radius defect. The surface F center is predicted to be more delocalized than that in the bulk. This is in agreement with previous findings for ionic oxides such as MgO [833] or Al₂O₃ [832] and results from the reduced Madelung potential and atomic coordination at the surface.

The oxygen vacancies on the SrTiO₃ (001) surface essentially change its properties, and they have to be taken into account when adsorption modeling. Unfortunately, the surface-defect calculations in the slab model are complicated due to the delocalized nature of the surface oxygen vacancy electron states. Such a study requires both sufficiently thick slabs (in modeling the surface) and large 2D supercells (in modeling the single vacancy on the surface).

While the theoretical study of the atomic and electronic structure of titanate surfaces is active, for manganites, such a study began only in 2004, as is seen in the next section.

11.3.3 Slab Models of LaMnO₃ Surfaces

Of primary interest for fuel-cell applications are the LaMnO₃ (LMO) surface properties, *for example*, the optimal positions for oxygen adsorption, its surface transport properties, as well as the charge-transfer behavior. In fuel-cell applications,

the operational temperature is so high ($T > 800$ K) that the LMO unit cell is cubic and thus Jahn–Teller (JT) lattice deformation around Mn ions and related magnetic and orbital orderings no longer take place.

The first *ab initio* calculation of cubic LaMnO_3 surface properties [834] has been made by the HF LCAO method for (110) LMO surface in the single-slab model. The extension of these calculations to the (001) LMO surface was made in [835]. The bulk cubic unit cell atoms are distributed over atomic planes (normal to the surface direction) in the following way: for the (110) surface— $\text{O}_2\text{—LaMnO—O}_2\text{—LaMnO}\cdots$; for the (001) surface— $\text{LaO—MnO}_2\text{—LaO—MnO}_2\cdots$ (see Fig. 11.4). In both cases, the surfaces are polar.

In LMO (110) surface calculations [834], the O_2 -terminated slab consisting of seven planes was taken, *that is*, four O_2 planes and three LaMnO planes. Such a symmetrical slab is nonstoichiometric, *that is*, it does not consist of an integer number of formula units. To restore the stoichiometry of the 7-plane slab, one oxygen atom has been removed from both O_2 planes terminating the slab, *that is*, the slab of three bulk primitive unit cells with periodically repeated surface oxygen vacancies was used. Such an approach is justified since it is well known that the polar surfaces are stabilized by surface defects and surface-atom relaxation. The surface energy E_s (per surface unit cell) for such a slab equals

$$E_s = \frac{1}{2} (E_{\text{O}}^{\text{slab}} - 3E_{\text{bulk}}) \quad (11.12)$$

where $E_{\text{O}}^{\text{slab}}$ and E_{bulk} are the total energies for the O-terminated slab and bulk unit cells, respectively. On the other hand, the defectless surfaces could be modeled using nonstoichiometric slabs: O_2 -terminated or LaMnO -terminated. In this case, the surface energy E_s could be calculated as the average:

$$E_s = \frac{1}{4} (E_{\text{O}_2}^{\text{slab}} + E_{\text{LMO}}^{\text{slab}} - 7E_{\text{bulk}}) \quad (11.13)$$

where $E_{\text{O}_2}^{\text{slab}}$ and $E_{\text{LMO}}^{\text{slab}}$ are the total energies of the slabs with O_2 and LaMnO terminations, respectively.

The comparison of energies for the stoichiometric and nonstoichiometric 7-plane slabs permits conclusions to be drawn on the role of surface oxygen vacancies in surface stabilization. The O-terminated slab consists of three Mn-containing planes; each Mn atom is supposed to have oxidation state +3, *that is*, 4 valence electrons are localized on Mn^{3+} ions. The UHF LCAO calculations have been performed for both the FM (the number of $\alpha - \beta$ electrons is $3 \times 4 = 12$) and the AFM ($\alpha - \beta = 4$ electrons) states. Since the SCF calculations of these slabs are extremely slow and time consuming, to a first approximation, the relaxed surface geometry optimized by means of the classical shell model [836] based on atom–atom potentials has been used. Since one of the two surface O atoms (per 2D unit cell) is removed, the remaining atoms reveal displacements not only perpendicularly to the surface but also in-plane.

Table 11.22 The effective atomic charges $Q(|e|)$ in four unrelaxed top layers of the LMO (110) surface, both stoichiometric O-terminated (Q_1) and nonstoichiometric O₂- and LaMnO-terminated (Q_2 and Q_3), as well as the relevant deviations of plane charges, $\Delta Q(|e|)$ from those in the bulk ($Q(\text{La}) = 2.56$; $Q(\text{Mn}) = 2.09$; $Q(\text{O}) = -1.55$)

Plane	Atom	Q_1	ΔQ_1	Q_2	ΔQ_2	Q_3	ΔQ_3
I	O	-1.16	0.39	-0.77	1.56	-1.86(O)	-1.40
						1.73 (La)	
						1.83 (Mn)	
II	La	2.45	-0.06	2.52	-0.06	-1.67 (O)	-0.24
	Mn	2.19		2.10			
	O	-1.60		-1.58			
III	O	-1.66	-0.16	-1.58	-0.06	-1.69 (O)	0.17
	O	-1.60		-1.58		2.56 (La)	
						2.40 (Mn)	
IV	La	2.54	-0.35	2.55	0.18	-1.63 (O)	-0.16
	Mn	1.87		2.31			
	O	-1.66		-1.58			

In slab calculations [835], the displacements in the first two top planes were taken into account, which are considerably larger than those in deeper planes. Similar to the bulk calculations, the FM stoichiometric (110) slab for the O termination turns out to be energetically more favorable than AFM, by 0.9 eV per Mn. The calculated O-terminated surface energy is 3.5 eV for the unrelaxed slab and 0.7 eV for the relaxed one, *that is*, the relaxation energy (per surface unit cell) is 2.8 eV.

Table 11.22 shows the effective atomic charges Q of slab atoms and the deviation of the plane charges ΔQ (per unit cell) from those calculated with the bulk atomic charges. For example, in plane II for the O-terminated stoichiometric surface, the effective charge of the La deviates from that in the bulk by 2.45 e —2.56 $e = -0.11 e$. The effective charges of Mn and O deviate from those in the bulk by 0.1 e and $-0.05 e$, respectively. That is, the LaMnO plane's charge deviates from that in the bulk by $-0.06 e$. This value characterizes the charge redistribution in near-surface planes compared to the bulk. For stoichiometric surfaces, the sum of ΔQ over all planes is zero. Thus, the effective charge of a surface O atom is considerably reduced with respect to that in the bulk. The charges of both metal atoms in the second plane are slightly more positive, which is almost compensated by the charge of a more negative O atom. Charges of the two O atoms in the third plane are close to those in the bulk. Surprisingly, in the central, fourth plane, the Mn charge turns out to be considerably (by 0.22 e) less positive than in the bulk. This is enhanced by the same trend for the O atoms, which results in a considerable ($-0.35 e$) effective charge of the central plane with respect to the bulk.

The calculation for the surface energy for the 7-plane nonstoichiometric slabs, obtained using (11.13), gives $E_s = 6.8$ eV, *that is*, about a factor of two larger than the surface energy of the stoichiometric slab. This demonstrates that oxygen vacancies strongly stabilize the polar (110) surface. The charge distribution for the nonstoichiometric O₂⁻ and LaMnO-terminated surfaces is summarized in

Table 11.22. As one can see, the effective charge of Mn in the central plane of the O_2 -terminated surface with respect to the bulk value is $-0.22 e$, *that is*, the same in absolute value but with the opposite sign to that on the O-terminated surface. The two surface O atoms share nearly the same charge as a single O atom possesses on the stoichiometric surface. Other planes are only slightly perturbed. Since the O_2 - and $LaMnO$ -terminated surfaces complement each other, their total charges (with respect to those in the bulk) are expected to be equal in magnitude but of the opposite signs, which indeed takes place.

Calculations for the asymmetric, 8-plane stoichiometric $LaO \cdots MnO_2$ slab show that the surface energy is larger by 1 eV than that for the stoichiometric 7-plane slab with surface vacancies. This means that the surface vacancies serve as a better stabilizing factor than the charge redistribution near the surface compensating for the macroscopic dipole moment. From the relevant charge redistribution, one can see that both surfaces of this 8-plane slab, the O_2 - and $LaMnO$ -terminated ones, are charged strongly positively with respect to the bulk charges, whereas the internal planes are charged mostly slightly negatively.

The LMO (001) surface was modeled in [835] by similar symmetric 7-plane slabs with two kinds of terminations ($LaO \cdots LaO$ and $MnO_2 \cdots MnO_2$) and an 8-plane $LaO \cdots MnO_2$ slab. The former is nonstoichiometric; the latter is stoichiometric (four bulk unit cells per surface unit cell). Unlike the (110) O-terminated surface, it is not easy to make the 7-plane (001) slab stoichiometric through introduction of surface vacancies. If we count the formal ionic charges, La^{3+} , Mn^{3+} , O^{2-} , these two slabs have the total charges of 1 e (LaO) and $-1 e$ (MnO_2). In the SCF calculations, slabs are assumed to be neutral by definition, which results in the electronic-density redistribution between atoms in different planes.

The calculated defectless surface energy for the (001) using (11.13) equals 2.04 eV. This is smaller by a factor of 3 than that for a similar nonstoichiometric (110) surface.

Analysis of the charge redistribution for the LaO - and MnO_2 -terminated (001) surfaces shows that the largest charge perturbation with respect to the bulk charges is observed for the top and bottom planes, similarly to the (110) case. The deviations of the effective atomic charges starting the second plane are quite small, of the order of 0.1–0.2 e . These two surface terminations are complementary, which is why the total charges of the LaO - and MnO_2 -terminated slabs are equal in absolute values and have opposite signs of $-1 e$ and 1 e , respectively. As to the use of the asymmetric, stoichiometric 8-plane slab $LaO \cdots MnO_2$, its main problem was believed to arise due to the macroscopic polarization caused by a dipole moment perpendicular to the surface as a consequence of the alternating oppositely charged (1 e , $-1 e$) planes. However, as was demonstrated for the $SrTiO_3$ (110) polar surface [837], the charge redistribution near the surface is able to cancel the macroscopic surface polarization. For this, the absolute value of the effective charge of the top plane should be smaller than that in the slab center. As was found in [835], the effective charge of the fourth MnO_2 plane of the 8-plane slab is $-0.86 e$, whereas that of the top LaO plane 0.37 e , *that is*, the condition is fulfilled and the (001) plane is stable. The same is true for the 8-plane (110) slab. For the 8-plane (001) slab, only the top and bottom planes of

a slab are considerably perturbed as compared to the bulk charges, charges in all the other planes are only slightly modified. The effective charges of the LaO and MnO₂ (top and bottom) planes are close in magnitude and opposite in sign. The relevant surface energy calculated using (11.2) turns out to be as small as 1.02 eV/cell for the FM state. This means that the (001) surface is stable and energetically favorable. The (001) surface energy in the AFM state is formally even lower, 0.83 eV. However, the relevant total energies for the bulk unit cell (per formula unit) and the slab in the AFM state are higher (by 0.22 and 0.56 eV, respectively) than the FM states.

The LCAO single-slab calculations [835] of the electronic structure of the polar LnMnO₃ (001) and (110) surfaces clearly demonstrate that the stoichiometric slabs have considerably lower energies than the nonstoichiometric ones. It should be stressed that the structural oxygen vacancies are energetically required and hence are essential elements of the (110) polar surface structure. Their formation makes the (110) slabs stoichiometric and energetically more favorable than the stoichiometric slabs stabilized by the near-surface electronic-density redistribution necessary to compensate the macroscopic dipole moment perpendicular to the asymmetric LaO $\cdots$ MnO₂ surfaces.

The comparative DFT B3PW LCAO (single-slab) and GGA PW (periodic-slab) calculations of LaMnO₃ (001) and (110) surfaces in slab models have been made in [838]; we refer the reader to this publication for details of the calculations. It is important that the B3PW LCAO and GGA PW calculations for the LaMnO₃ surfaces show reasonable agreement for atomic displacements, effective charges (in the PW calculations, Bader analysis was used), and surface energies. The effective charges of surface atoms markedly depend on the surface relaxation and less on the particular (FM or AAF) magnetic configuration. The HF-based conclusion (see discussion above) that the polar (001) surface is energetically more favorable than the (110) one was confirmed. This conclusion is important for the modeling of surface adsorption and LaMnO₃ reactivity. The surface relaxation energy is typically of the order of 1–1.5 eV (per square unit a^2 , where a is the cubic lattice parameter), *that is*, much larger than the tiny difference between various magnetic structures. Moreover, the calculated surface energy for the slab built from orthorhombic unit cells is close to and even slightly larger than that for the cubic unit cells. These two facts justify the use in surface and adsorption modeling of slabs built from the cubic cells. This is a very important observation since the detailed adsorption and migration modeling, *for example*, for surface O atoms at moderate coverages that is relevant for fuel-cell applications, is very time consuming even for the smallest slab thicknesses.

Chapter 12

LCAO Calculations on Uranium Nitrides

The pseudopotentials constructed in relativistic calculations for free atoms (relativistic core pseudopotentials—RCP) are used in the scalar-relativistic calculations of molecules and crystals, on the assumption that RCP rather accurately reflects one-electron states and properties of a system. The validity of such an approach is demonstrated by the comparison of the results obtained in the scalar-relativistic and relativistic calculations of the UF_6 molecule. The results of LCAO DFT scalar-relativistic calculations on the UO_2 crystal and the comparative study of UN, U_2N_3 , and UN_2 crystals are discussed. The calculations of the UN crystal (001) surface allow one to study the O_2 molecule dissociation and the diffusion path of O_{ads} on both perfect and defective UN(001) substrates for the purpose of understanding the atomistic mechanism of oxidation by means of substituting the surface N ions for the O ions.

12.1 Bulk Crystals

12.1.1 UF_6 Molecule and UO_2 Crystal

We saw in Chap. 8 that relativistic calculations of molecules and crystals containing heavy atoms involve solving the Dirac relativistic equation and consequently present great difficulties. As a rule, such calculations use pseudopotentials constructed in relativistic calculations for free atoms (relativistic core pseudopotentials—RCP).

In particular, the relativistic pseudopotentials were used in [410, 878, 1036] when the scalar-relativistic LCAO calculations of the electronic structure of the AnF_6 molecules ($\text{An}=\text{U}, \text{Np}, \text{Pa}$) and the actinide dioxide AnO_2 ($\text{An}=\text{Th}-\text{Es}$) crystals were made. In addition to that, it was assumed that RCP rather accurately reproduces the one-electron states and properties of a system in consideration. The validity of such a supposition is studied in [1037] using the UF_6 molecule. Uranium hexafluoride UF_6 became subject of numerous experimental and theoretical studies owing to

the fact that it is used in the enrichment of uranium with a molecular laser. The difficulties in the calculation of the electronic structure of this molecule are connected both with the necessity to take into account the relativistic effects and with the influence of electronic correlation effects in the case of the localized f -electrons of the uranium atom.

The impact of the relativistic effects on the electronic structure of molecules containing actinide atoms is of two kinds. First, the orbital energies of $5f$ and $6d$ orbitals increase more considerably than the energies of $6p$ and $7s$ orbitals. It results in a greater delocalization of $5f$ orbitals and in their active participation in the chemical bonding. Therefore, high oxidation states of the heavy atoms are an essential feature of actinide compounds. Second, the relativistic effects result in the splitting of the one-electron levels under the influence of spin–orbit coupling; this splitting proves to be greater for $6p$ orbitals than for $5f$ orbitals. Both effects mentioned influence the spectrum of the one-electron energies of a molecule; as was demonstrated in [1037] with uranium hexafluorides, the results of relativistic and nonrelativistic calculations were compared.

We refer the reader to the review [1038] and the papers [1039, 1040] for a more detailed acquaintance with the results of the relativistic calculations of molecules containing actinide atoms in the local-density formalism. In the relativistic calculations of the molecules containing heavy atoms, the one-electron approximation [the Dirac–Hartree–Fock method (DHF)] is used; see Sect. 8.3 and references therein. The DHF method is a relativistic analog of the Hartree–Fock (HF) method widely applied to nonrelativistic calculations of molecules. The solutions of the DHF equation are four-component spinors in which two components (large) refer to electron states and two small components – to positron states. As fully relativistic (four-component) calculations demand huge computational efforts, several quasirelativistic (two-component) approximations have been proposed in which only large components are treated explicitly (see Sect. 8.3.1). The two-component relativistic calculations involve the solution of the Pauli equation, which is an approximation to the DHF equation, and its Hamiltonian is given by Eq. (12.1):

$$H = \frac{p^2}{2m} + V + \frac{\hbar}{4m^2c^2} \boldsymbol{\sigma} [(\nabla V) \times \mathbf{p}] + \frac{\hbar^2}{8m^2c^2} (\nabla^2 V) - \frac{1}{8m^3c^2} p^4 \quad (12.1)$$

The nonrelativistic potential V in this equation can be both the one-electron potential of the HF method and the exchange–correlation potential of the density-functional theory (DFT) method in the Kohn–Sham approximation which allows the electron correlation to be taken into account.

The last two summands in Eq. (12.1) describe the scalar-relativistic (one-component) corrections to the nonrelativistic Hamiltonian (the Darwin correction and the correction for the dependence of mass on rate) and do not change its symmetry. Therefore, the one-electron states of a molecule in a scalar-relativistic calculation are classified by the irreducible representations of the point group G of molecule symmetry, in which the unit element E corresponds to the rotation by the angle 2π . Taking into account the scalar-relativistic corrections does not result in

any additional splitting of the one-electron levels of the molecule but can lead to their shifting as compared to the nonrelativistic calculation. In this case, the extent of mixing the molecular orbitals of the same symmetry and the coefficients defining the atomic contributions in molecular orbitals can also change.

The third summand in Eq. (12.1) describes the interaction of the electron magnetic (spin) and orbital moments (spin–orbit coupling). This summand, containing the operator of the impulse $\mathbf{p}$ and two-component Pauli's matrices σ , changes the Hamiltonian symmetry and, as a consequence, the classification of one-electron states. For example, atomic one-electron states are classified now not by the orbital moment l but by the total moment $j = l + 1/2, l - 1/2$. When account is taken of spin–orbit coupling, the calculations of both the atom and the molecule become two component. The symmetry group of Hamiltonian (12.1) for the molecule becomes the double point group $\overline{G}$, and the two-component spinors (molecular orbitals in the relativistic calculation) are transformed by the irreducible representations of the group $\overline{G}$. In a double point group, the unit operation E is the rotation by the angle 4π , and the number of elements is doubled (now the non-unit element $\overline{E}$ corresponds to the rotational by the angle 2π). The irreducible representations of the double point groups $\overline{G}$ are well known [1041]; they are also called double-valued representations of the point groups G , meaning that the characters of these representations for the elements E and $\overline{E}$ differ in sign. Ordinary (single-valued) irreducible representations of point groups are simultaneously irreducible representations of double groups in which equal characters correspond to the E and $\overline{E}$ elements. As the dimensions of single- and double-valued representations of point groups, as a rule, differ from each other, the inclusion of spin–orbit coupling can lead to the splitting of one-electron levels as compared to nonrelativistic calculations. In the octahedral molecule UF_6 (symmetry group O_h), the atomic s , p , d , and f orbitals of the uranium atom are transformed by the irreducible representations a_{1g} , t_{1u} , e_g , t_{2g} , a_{2u} , t_{1u} , t_{2u} , respectively (the splitting of d and f levels is connected with the reduction of the symmetry group of a free atom in a cubic field). When the spin–orbit coupling is taken into account, the symmetry of the uranium atom states corresponds to the irreducible representations of the double group $\overline{O_h}$ obtained as the direct product $D^l \times D_{1/2} = D^{l+1/2} + D^{l-1/2}$ where $D^{l+1/2}$ and $D^{l-1/2}$ are the irreducible representations of the double group, $l = 0, 1, 2, 3$ for the s , p , d , and f orbitals, respectively.

Using the table of the double group $\overline{O_h}$ characters, one can find the symmetry of the atomic orbitals with spin–orbit coupling taken into account. It appears thus that the levels of s orbitals are not split (they pass into spinors transformed by the two-dimensional representation $\overline{e}_{1g}$ of the double group). For p levels of the t_{1u} symmetry in the double group, twofold $\overline{e}_{1u}$ and fourfold $\overline{g}_u$ levels are obtained. The following symmetry of states of the double group arises from d levels: $\overline{g}_g$ (for e_g orbital), $\overline{e}_{2g}$, and $\overline{g}_g$ (for t_{2g} orbital). Finally, the representations $\overline{e}_{2u}(a_{2u})$, $\overline{e}_{1u}, \overline{g}_u(t_{1u}), \overline{e}_{2u}$, and $\overline{g}_u(t_{1u})(t_{2u})$ correspond in the double group to the representations a_{2u} , t_{1u} , and t_{2u} (f orbitals). Using the site-symmetry approach [13] for fluorine

orbitals, it is possible to show that for the point group, O_h s and p_z fluorine orbitals generate states with the symmetry a_{1g} , e_g , t_{1u} , and p_x and p_y orbitals—states with the symmetry t_{1g} , t_{2g} , t_{1u} , and t_{2u} . In the double group, $\overline{O}_h$ s and p_z orbitals of six fluorine atoms (local group C_{4v}) generate molecular orbitals with the symmetry $\overline{e}_{1g}, \overline{e}_{1u}, \overline{g}_g, \overline{g}_u$, $\overline{e}_{1g}$, and p_x and p_y orbitals—states with the symmetry $\overline{e}_{1g}, \overline{e}_{2g}, \overline{e}_{1u}, \overline{e}_{2u}, 2\overline{g}_g, 2\overline{g}_u$.

The first full-electron relativistic LCAO calculations of uranium hexafluoride were made with the use of the MOLFDIR computer code [1042]—practically simultaneously by the DHF method [1043] and the DHF method with the superposition of configurations [1044].

The above-considered symmetry connection of one-electron states in relativistic and scalar-relativistic calculations is illustrated in Table 12.1, where one-electron energies for the full-electron HF [1043] and the DHF calculations [1043, 1044] are compared. These calculations were made for the experimental R_{U-F} distance of 1.999 Å in both the nonrelativistic HF and relativistic DHF variants. Table 12.1 allows one to draw the following conclusions. In accordance with the earlier relativistic calculations with a local exchange, the splitting of the $6p$ uranium atom levels (7.40 eV in [1043] and 7.50 eV in [1044]) is noticeably greater than the splitting of the $5f$ levels (0.33 eV for t_{2u} and 0.30 eV for t_{1u} levels [1044]). It was noted in [1043] that the earlier relativistic scattered wave calculations with a local exchange gave an overestimated (12.5 eV) splitting of the uranium $6p$ levels owing to the spin–orbit coupling (the experimental value is about 10 eV). At the same time, the nonrelativistic calculation by the HF method has shown that the local exchange approximation X_α used earlier distorts the sequence of one-electron levels, which, in addition, essentially depends on the choice of the local exchange potential parameters [1044]. According to the full-electron nonrelativistic calculation by the HF method, the dissociation energy of the UF_6 molecule is 13.7 eV, which reproduces only 43% of the experimental value. If relativistic effects are taken into account this value increases to 23.5 eV (73% of the experimental value), and the energies of MOs corresponding to the core states $1s$, $2s$, and $3s$ of the uranium atom are essentially reduced as compared to the HF calculation. At the same time, for the MOs that are higher in energy (arising from $6s$ and $6p$ states of uranium atom), the reduction is noticeably less. For the MOs containing the filled $3d$, $4d$, $5d$, and $4f$ orbitals of the uranium atom, the one-electron energies increase as a consequence of the increasing screening of the nucleus by the inner electrons when the relativistic effects are taken into account. It is also concluded on the basis of the calculations [1043, 1044] that the $5f$, $6d$, and $7s$ valence electrons of the uranium atom only slightly participate in the chemical bonding of the UF_6 molecule in the ground state. This conclusion is illustrated by Table 12.1, showing the weights of AOs (%) in the resulting molecular orbitals.

However, the charge on the uranium atom of +2.8 calculated after Mulliken is far from the purely ionic value +6, but it appears more ionic than that obtained in the nonrelativistic HF calculations (+2.1). Similarly to [1043], in [1044], an increase in the ionic character of uranium–fluorine bonds was also obtained when relativistic

Table 12.1 One-electron energies (au) for the UF₆ molecule in nonrelativistic HF [1043], relativistic DHF [1043,1044], and scalar-relativistic pseudopotentials SK60 [1051], MT (60,78) [1076]

O_h	HF(AE) [1040]	SK60 (MT60)(MT78)	$\overline{O}_h$	DHF(AE) [1038]	U_s	U_p	U_d	U_f	F_s	F_p
$U(6s)a_{1g}$	-1.892	-2.517 (-2.506)(-2.508)	$\overline{e}_{1g}$	-2.522	96.3				1.9	1.8
t_{1u}	-1.667	-1.692 (-1.694)(-1.696)	$\left\{ \begin{array}{l} \overline{e}_{1u} \\ \overline{g}_u \end{array} \right.$	$\left\{ \begin{array}{l} -1.802 \\ -1.696 \end{array} \right.$		58.6 13.8			38.9 84.3	2.5 1.8
e_g	-1.633	-1.636 (-1.635)(-1.638)	$\overline{g}_g$	-1.650			0.8		98.0	1.2
a_{1g}	-1.519	-1.614 (-1.613)(-1.615)	$\overline{e}_{1g}$	-1.625	0.8				98.6	0.7
$U(6p)t_{1u}$	-1.323	-1.322 (-1.321)(-1.316)	$\left\{ \begin{array}{l} \overline{e}_{1u} \\ \overline{g}_u \end{array} \right.$	$\left\{ \begin{array}{l} -1.520 \\ -1.245 \end{array} \right.$		38.0 75.1			62.0 16.6	
e_g	-0.755	-0.777 (-0.776)(-0.770)	$\overline{g}_g$	-0.778			14.4		3.2	82.3
t_{2g}	-0.732	-0.755 (-0.750)(-0.752)	$\left\{ \begin{array}{l} \overline{e}_{2g} \\ \overline{g}_u \end{array} \right.$	$\left\{ \begin{array}{l} -0.759 \\ -0.760 \end{array} \right.$			11.2 11.9			88.8 88.1
t_{1u}	-0.728	-0.726 (-0.725)(-0.733)	$\left\{ \begin{array}{l} \overline{e}_{1u} \\ \overline{g}_u \end{array} \right.$	$\left\{ \begin{array}{l} -0.735 \\ -0.732 \end{array} \right.$				12.8 14.3	1.0 0.9	86.2 84.8
t_{2u}	-0.717	-0.709 (-0.708)(-0.714)	$\left\{ \begin{array}{l} \overline{e}_{2u} \\ \overline{g}_u \end{array} \right.$	$\left\{ \begin{array}{l} -0.718 \\ -0.717 \end{array} \right.$				8.6 8.7		91.4 91.3
a_{1g}	-0.684	-0.708 (-0.708)(-0.697)	$\overline{e}_{1g}$	-0.708	6.0				1.4	92.6
t_{1g}	-0.610	-0.671 (-0.675)(-0.680)	$\left\{ \begin{array}{l} \overline{e}_{1g} \\ \overline{g}_g \end{array} \right.$	$\left\{ \begin{array}{l} -0.678 \\ -0.680 \end{array} \right.$					100.0 100.0	
HOMO t_{1u}	-0.583	-0.649 (-0.645)(-0.645) (17.66 eV)	$\left\{ \begin{array}{l} \overline{e}_{2u} \\ \overline{g}_u \end{array} \right.$	$\left\{ \begin{array}{l} -0.679 \\ -0.636 \end{array} \right.$		6.6 11.2		4.2 9.0	0.5	88.7 79.8
q	3.85/ -0.64									
ΔE	15.48		(-17.31 eV) 14.88							

(continued)

Table 12.1 (continued)

	HF(AE) [1040]	SK60 (MT60)(MT78)	$\overline{O}_h$	DHF(AE) [1038]	U_s	U_p	U_d	U_f	F_s	F_p
LUMO a_{2u}		−0.080 (−0.068)(−0.114)	$\overline{e}_{2u}$	−0.089				99		1.0
t_{2u}		−0.055 (−0.051)(−0.098)	$\left\{ \begin{array}{l} \overline{e}_{2u} \\ \overline{g}_u \end{array} \right.$	$\left\{ \begin{array}{l} -0.057 \\ -0.069 \end{array} \right.$				96 89.8		4.0 9.4
t_{1u}		−0.034 (−0.026)(−0.075)	$\left\{ \begin{array}{l} \overline{e}_{1u} \\ \overline{g}_u \end{array} \right.$	$\left\{ \begin{array}{l} -0.020 \\ -0.031 \end{array} \right.$		1.4 1.7		86.9 95.9		11.7 12.4

effects were taken into account (the Mulliken charge on the atom increases from +2.2 up to +2.7).

It is evident from the aforesaid that the consideration of relativistic effects in the full-electron calculation of the UF_6 molecule is rather essential. In [1044], alongside the relativistic effects in the full-electron calculation, the effects of electron correlation were also considered by the CI method. The full-electron calculation by the DHF method with a superposition of configurations makes it possible to take into account the correlation effects and to obtain the photoelectron spectrum of uranium hexafluoride in the good agreement with the experiment. In the later relativistic calculations [1045, 1046] of the UF_6 molecule, the correlation effects were considered using the hybrid density functionals PBE0 [361] and B3LYP [1047], which also led to a satisfactory agreement of the calculated and experimental photoelectron spectra. Thus, the complete consideration of the double group symmetry [1046] in relativistic calculations with the hybrid functional B3LYP made it possible to essentially reduce the number of calculated molecular integrals and to carry out the optimization of the interatomic distances in the UF_6 molecule. The value of R_{U-F} 2.012 Å, found in the full-electron calculation [1046], practically coincides with the value 2.014 Å obtained in the scalar-relativistic calculation [1048] by the B3LYP method with the uranium atom pseudopotential replacing 78 core electrons.

The consideration of the relativistic effects in compounds of heavy atoms is most easily carried out in scalar-relativistic (one-component) calculations with the use of the relativistic effective core potential (RECP). Following [1037], we shall discuss a problem of practical importance, that is, to what extent the application of the RECP of an uranium atom to scalar-relativistic calculations by the HF method is useful in reproducing the spectrum of one-electron energies found in the full-electron relativistic calculation by the DHF method. From Eq.(8.19) in Sect. 8.3, it is seen that the nonrelativistic or scalar-relativistic pseudopotential of an atom is represented in the form of the sum of Coulomb C , local V_{loc} , and semilocal V_{sl} contributions:

$$V_{\text{PS}}(\mathbf{r}) = C + V_{\text{loc}} + V_{\text{sl}} = -\frac{Z_N}{r} + \sum_{k=1}^M r^{n_k-2} C_k \exp(-\alpha_k r^2) + \sum_{l=0}^3 \left[\sum_{k=1}^{M_l} r^{n_{kl}-2} C_{kl} \exp(-\alpha_{kl} r^2) \right] \hat{P}_l \quad (12.2)$$

Here, Z_N is the core charge. The potentials V_{loc} and V_{sl} in Eq. (12.2) are written in the form of the sum of products of polynomials of powers r by Gaussian functions, the nonlocal contribution to the pseudopotential contains the projection operator $\hat{P}_l$ for each value of the orbital quantum number l . The summation over l is usually carried out up to $L + 1$, where L is the maximal orbital number for valence electrons in an atom (for the uranium atom $L = 3$, i.e., the semilocal pseudopotential V_{sl} contains S, P, D, F, and G contributions). The coefficients C_k , C_{kl} , and the orbital exponents α_k and α_{kl} are determined in such a way as to minimize the difference between the analytically given pseudopotential and that found by the numerical solution of Hartree–Fock or Dirac–Fock equations for the atom. The numerical solutions of the specified equations (pseudo-orbitals) for the constructed pseudopotential are approximated by a linear combination of Gaussian functions with coefficients providing the proximity of the numerical and analytically given pseudo-orbitals.

Depending on the number of electrons considered as core electrons, pseudopotentials for large core (LC) and small core (SC) are distinguished. For the LC potentials, all electrons, except for the valence, are included in core (for the uranium atom with $Z = 92$ and six valence electrons in the ground-state configuration $5f^3 6d^1 7s^2$, this potential is designated RECP86). However, LC pseudopotentials in most cases appear too crude for the description of an atom. In the case of uranium, SC pseudopotentials RECP78 are normally used (8 electrons in the configuration $6s^2 6p^6$ are excluded from the core) and RECP60 (18 electrons in the configuration $5s^2 5p^6 5d^{10}$ are also excluded from the core). In the latter case, 14 electrons of $4f$ orbitals are assigned to the core by virtue of their greater localization compared to $5s$, $5p$, and $5d$ orbitals. A comparative study of various LC and SC pseudopotentials of uranium was made in [1049] with the uranyl UO_2^{2+} cation. The authors of that work unambiguously concluded that the use of the LC pseudopotentials for the uranium atom results in essential errors in calculating both the geometrical characteristics and electronic-structure characteristics of the uranyl cation and recommend the use of SC pseudopotentials in the calculations of uranium containing molecules.

When constructing the pseudopotential of an atom, of special importance are criteria which are used to determine the proximity of the results calculated with the pseudopotential to those of the full-electron calculation. For the uranium atom, the SC pseudopotentials RECPHW78 of Hay and Wadt (HW) [1050] and the SC pseudopotentials RECPSK60 of the science teams Stuttgart–Koln (SK) [1051, 1052] are known. When constructing the RECPHW78 pseudopotentials, a scalar-relativistic calculation of an atom is carried out, and at each l value, a criterion

is used, according to which the one-electron energies of electrons not included in the core should be close to the energies obtained in the full-electron scalar-relativistic calculation of the atom ground state. This criterion does not take into account the fact that when the atom is involved in a chemical bond, the valence orbitals of the ground state are deformed, and a nonzero charge arises on the atom. Therefore, in constructing a pseudopotential, it is necessary to consider both the excited states of the free atom and the states of the ions. From this point of view, an SK pseudopotential is more accurate (it is also named energy consistent), as its parameters are optimized with respect to the total energy of electrons not included in the core for the ground and several excited states of both the neutral atom and ions. In the most complete form, the SK pseudopotential contains both one-component (nonrelativistic and scalar-relativistic parts); see Eq. (12.2) and contributions describing the spin-orbit coupling and core-polarization effects. The use of such a pseudopotential is connected with the requirement that the calculation of a molecule should also be relativistic (at least, two component).

A scalar-relativistic calculation of the UF_6 molecule was carried out in [1037] using the RECPSK60 relativistic potential taken from [1051, 1052]. The Gaussian03 program [102] was used. In the selected pseudopotential $V_{\text{loc}} = 0$ and in the semilocal component V_{sl} , all the parameters n_{kl} are 2. For the fluorine atom, the basis 6-311G* from [1052] including the polarizing d -function was used. In Table 12.1, the one-electron energies for the valence electrons calculated with the relativistic pseudopotential RECPSK60 are compared with similar energies found in the full-electron relativistic calculations [1043, 1044]. In addition to that, the influence of both the introduction of the pseudopotential for core electrons and the quality of the consideration of relativistic effects by means of the relativistic pseudopotential on the one-electron energies of valence electrons is revealed. It is seen from Table 12.1 that the order of levels found in the full-electron calculation by the DHF method is correctly transferred in the calculation with the relativistic pseudopotential. Moreover, the one-electron energies of the occupied states are also rather well transferred. Thus, the energy of the higher occupied orbital (HOMO) is equal to -17.66 eV in the calculation with the pseudopotential and -17.03 eV in the full-electron calculation. In Koopmans approximation, these energies give an estimate of the first ionization potential, which was experimentally found to be 14.11 eV. The correct calculation of this value demands the electron correlation to be taken into account. It is seen from Table 12.1 that the electron correlation effects are small for those states in which the main contribution is brought by the functions of fluorine atoms. So, the spin-orbit splitting for the t_{1g} orbital is only 0.011 au (0.3 eV).

The results shown in Table 12.1 were obtained with the use of basis functions for free atoms and do not take into account their distortion in a molecule upon chemical bonding. This distortion can be taken into account by optimizing of the atomic basis. The methods of the atomic basis optimization for molecules and crystals and the results of such optimization for the UF_6 molecule are discussed in [1037]. Powell's method [1058] was used, which is the most effective. The selected set of uranium and fluorine atomic Gaussian functions includes 20 noncontracted Gaussian orbitals with exponential parameters optimized by energy minimization in

Table 12.2 Values of the U–F bond length (Å), the first ionization potential (eV), the electron affinity (eV), and the atomization energy (eV) in the uranium hexafluoride molecule

Calculated characteristics of the molecule	Calculation method			Experiment
	RHF	PBE	PBE0	
$R_{\text{U-F}}$ in the initial basis	1.985	2.021	1.993	1.999 [1053]
$R_{\text{U-F}}$ in the optimized basis	1.984	2.022	1.994	
IP in the initial basis	17.5	10.3	12.2	14.1 [1054]
IP in the optimized basis	17.4	10.3	12.2	
Affinity in the initial basis	7.6	4.6	5.6	4.9–8.1 [1055, 1056]
Affinity in the optimized basis	7.5	4.5	5.5	
Atomization energy in the initial basis	25.4	36.4	33.0	31.9–32.6 [1057]
Atomization energy in the optimized basis	26.2	36.4	33.4	

the framework of the HF method. To find out the dependence of these parameters on the particle charge, the same procedure was used for the cation and the anion of uranium hexafluoride. The optimization was carried out at experimental equilibrium geometry of uranium hexafluoride.

The question as to extent to which the atomic orbitals and geometry of a system can be independently optimized is of certain practical interest. The calculations [1037] show that the optimality of orbitals only slightly depends on the optimality of the geometrical structure of the system. In this respect, the most indicative are calculations of the uranium hexafluoride cation. When an electron is removed, the geometry of uranium hexafluoride undergoes very serious changes: one of the U–F bonds is essentially (by approximately 0.7Å) elongated, and the symmetry group of the equilibrium configuration is reduced to C_{2v} . In addition to that, the optimized values of exponential parameters practically do not vary in passing from $\text{UF}_6^+(O_h)$ to $\text{UF}_6^+(C_{2v})$.

To find out how much the optimization of the noncontracted part of the Gaussian basis affects the properties of the UF_6 molecule calculated in various approximations, the first vertical ionization potential (IP), the electron affinity, the atomization energy, and the frequencies of normal vibrations of the UF_6 molecule were analyzed in [1037]. The computational methods there used were the restricted HF (RHF) method, the PBE option of the DF method in the PBE variant (with a gradient correction in the correlative part), and the hybrid PBE0 method. The results of the calculations are presented in Tables 12.2, 12.3. It is seen from these tables that the optimization of the basis influences the characteristics of the UF_6 molecule under consideration only slightly. The correlation corrections to the energy introduced within the limits of the density-functional method and the hybrid methods lead to a substantial improvement of the values of the ionization potential and the atomization energy.

Using the UF_6 molecule as an example, we have seen that relativistic effects play an essential role in the determination of the electron properties of molecules containing an uranium atom. These effects were taken into account in one-component (scalar) relativistic calculations [1061] to determine the bond lengths and harmonic vibrational frequencies of UO_2^{2+} and AnF_6 ($\text{An} = \text{U}, \text{Np}, \text{Pu}$) using various DFT

Table 12.3 Frequencies of normal vibrations (cm^{-1}) of the uranium hexafluoride molecule calculated with the initial (I) and optimized (II) bases

Irreducible representation	Calculation method						Experiment [1058]
	RHF		PBE		PBE0		
	I	II	I	II	I	II	
T_{2u}	143.98	141.18	119.47	119.54	133.60	133.30	143
T_{1u}	201.13	197.53	162.96	162.76	178.49	177.59	186
T_{2g}	222.42	222.20	180.89	181.00	195.18	195.17	200
E_g	546.16	551.54	512.98	520.41	537.02	543.01	534
T_{1u}	658.53	661.95	587.93	595.09	627.81	632.79	626
A_{1g}	741.06	746.22	623.26	629.49	676.50	680.77	667

calculations with relativistic effective core potentials RECPs and extended basis sets. The calculated spectroscopic constants using small-core RECPs compare favorably with the available all-electron relativistic results for UO_2^{2+} and UF_6 . The results using the hybrid functionals are in very good agreement with the experimental data for the geometries and vibrational frequencies of the AnF_6 systems. The performance of pure gradient-corrected functionals is poor, even worse than that of the local-density functional for the geometries and vibrational frequencies. The hybrid functional calculations give correct results for the vibrational frequencies order with only small quantitative deviations from the experimental data. The local-density functional provides reliable frequencies for the stretching modes but underestimates the frequencies for the bending modes. The pure gradient-corrected functionals underestimate the frequencies for all the stretching and bending modes. The large-core RECP calculations provide short bond lengths and a rather poor description of the vibrational frequencies relative to the small-core RECP calculations for UO_2^{2+} and UF_6 .

It is obvious that the relativistic effects should be significant for the electronic-structure calculations of the crystals containing an uranium atom. The properties of the crystalline UF_6 are poorly known, and though crystals of such composition exist, they evidently have a molecular structure, and their electron properties are first of all defined by the electronic structure of the molecules, whereas the intermolecular interactions occur due to van der Waals forces. Therefore, to analyze the contribution of the relativistic effects into the properties of uranium containing crystals, the uranium dioxide UO_2 was selected in [1037], as its molecular and electronic structure has been thoroughly studied, both experimentally [1059] and theoretically for the bulk UO_2 (pure and defective) [410,878,1060,1062,1064,1065] and UO_2 surface [1063,1069].

The crystal UO_2 has fluorite structure and is a the Mott–Hubbard dielectric with an energy gap width of 2.5 eV. One can expect that the chemical bond between uranium and oxygen atoms has a partially covalent character. It has been proved to be true by the quantum-chemical calculations: the charge on the oxygen atom obtained on the basis of the Mulliken population analysis varies (depending on the computational method and basis) from -1.1 to -1.4 e. In [1037], the calculations of

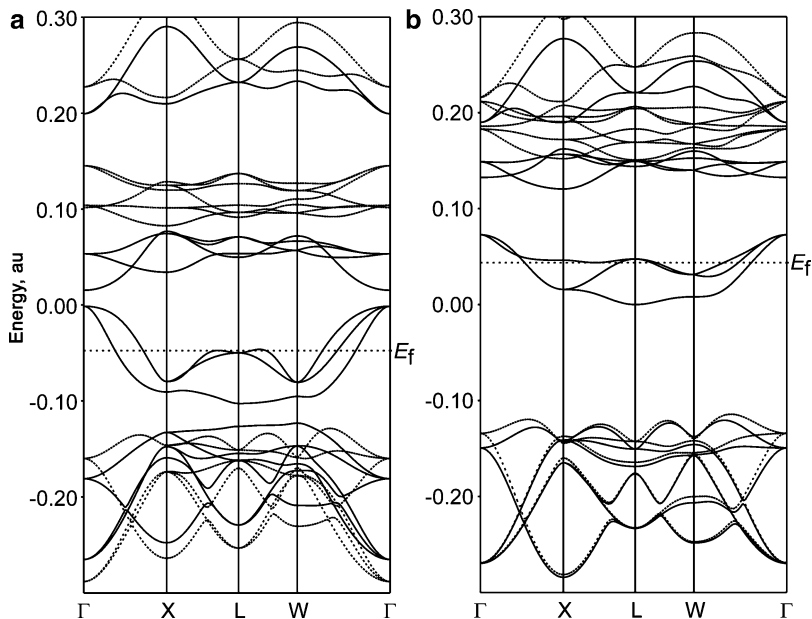


Fig. 12.1 Band structure of the ferromagnetic phase of UO_2 crystal calculated using (a) nonrelativistic and (b) scalar-relativistic pseudopotentials for the uranium atom

the UO_2 crystal were made on the basis of the hybrid PBE0 method [398] using the same pseudopotential RECPSK60 [1051] of the uranium atom as in the calculations of the UF_6 molecule. The contracted form of the basis AOs of the uranium atom [1051, 1052] was retained but adapted for crystalline calculations. The s -, p -, and d -diffuse functions (with exponents of less than 0.1) and also the f -function with exponents of less than 0.2 were excluded from the basis set. The Gaussian set 8-411* was used for the oxygen atom; it was also specially optimized for the calculations of crystalline systems in [637]. In all the calculations, the spin polarization was taken into account. The calculations showed that when the cubic symmetry is preserved, the ferromagnetic phase of the crystal with two unpaired f -electrons localized on each uranium atom proves to be the most stable one. In such state, uranium dioxide is the conductor.

The energy-band structures calculated for the experimental geometry of the crystal using nonrelativistic and scalar-relativistic pseudopotentials [1066] are presented in Fig. 12.1. In both cases the two unpaired electrons occupy the states of three upper bands arising preferentially from the f states of the uranium atom and possessing the point symmetry t_{1u} in the center of the Brillouin zone that corresponds to the irreducible representation Γ_5 of the crystal space group. In the point Γ of the Brillouin zone, these three states are degenerated. The comparison of the energy-band structures in Fig. 12.1 shows that the consideration of the relativistic corrections to the pseudopotential essentially changes the width of the

Table 12.4 Comparison of the calculated (for the ferromagnetic phase) and experimental properties of the UO_2 crystal

Property	Nonrelativistic pseudopotential	Scalar-relativistic pseudopotential	Experiment [1059]
Lattice constant a , Å	5.63	5.41	5.46
Bulk modulus of elasticity B , HPa	123	224	207
Cohesive energy E_{coh} , eV	12.1	20.2	22

specified f -subzones in the region of the Fermi level and also their distance from the nearest occupied (consisting preferentially of the $2p$ states of oxygen atoms) and unoccupied zones. When the relativistic corrections are taken into account, these three states form a rather narrow subzone, which is rather far removed (in energy) from both the lower occupied and the upper free states. This fact agrees well with experimental data [1059] and the available relativistic calculations [1067, 1068] of the UO_2 crystal. The reduction of symmetry (that formally corresponds to the doubling a primitive cell) results in the decrease in the energy of one of the three specified zones, and, as a result of so-called antiferromagnetic coupling, the crystal turns out to be a dielectric with a rather wide forbidden bandgap. In Table 12.4, the properties of the bulk UO_2 crystal found with the use of the nonrelativistic and scalar-relativistic forms of the pseudopotential of uranium core are compared. The data of the table convincingly testify that the use of the nonrelativistic form of the pseudopotential leads to unsatisfactory results for the main properties of the crystal, whereas the scalar-relativistic form within the limits of the hybrid exchange-correlation PBE0 functional results in a good agreement between the observed and the calculated values.

Thus, it has been demonstrated that the conclusion about the importance of using the relativistic form of the pseudopotential fully retains its validity when one passes from molecules to crystals.

12.1.2 Uranium Nitrides UN , U_2N_3 , UN_2

Crystalline uranium nitrides are intensively studied experimentally [1070–1073], as promising fuel materials for the Generation-IV fast reactors. The theoretical studies of these systems are difficult as they require taking into account the relativistic character of the U atom core electrons and the strong electron–electron correlation. Moreover, it is well known that the convergence of the self-consistent field procedure is difficult in the materials with closely lying partially occupied metal f orbitals [410]. The majority of nonempirical calculations are made on actinide dioxides, both perfect and defective; see [878, 1074–1077] and the references therein. Conversely, for nitrides, what is currently known is mainly the calculations of UN made by methods that are traditional for solid-state theory: KKR [1078],

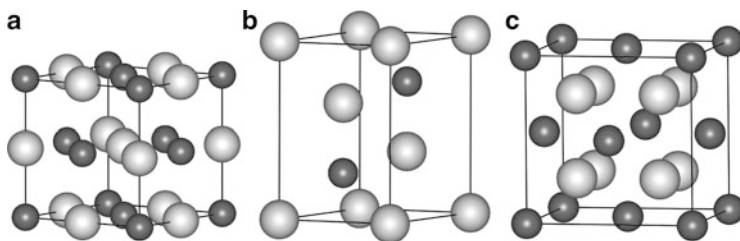


Fig. 12.2 (a) UN, space group $Fm\bar{3}m$; (b) U_2N_3 , space group $P\bar{3}m1$; and (c) UN_2 , space group $Fm\bar{3}m$. U atoms—dark balls and N atoms—light balls

LMTO [1079], plane waves (PW) [1080–1082], and LAPW [1083, 1084]. Recent LCAO calculations [1074, 1076] allowed a more careful study of the mixed metallic-covalent chemical bonding in the UN crystal. The calculations on experimentally known relevant stoichiometric U_2N_3 and UN_2 crystalline compounds are made recently [1081, 1082] in the PW basis. A recent LCAO UN_2 calculation [1074] uses a numerical atomic basis. The first LCAO electronic-structure calculations of crystalline U_2N_3 compounds were performed in [1085]. In the three uranium nitrides mentioned, the valence of U changes from 3 to 6. The comparative LCAO calculations of all the three crystals allow us to understand the changes in chemical bonding brought about by the U valence increase. It is also important to give an answer the following question: is it possible to use the free U atom basis set (corresponding to the pseudopotential chosen) with the diffuse Gaussian-type orbitals removed or is it necessary to optimize BS?

We now proceed to discuss in more detail the results of LCAO DFT calculations [1085] in the comparative study of UN, U_2N_3 , and UN_2 crystals. A basis-set optimization was made for the UN crystal. Two small-core RECPs were used for the U atom: the energy adjusted RECP by Stuttgart–Cologne (SC) group [1051], SC60, and the generalized shape-consistent RECP by Mosyagin–Titov (MT), MT60 [1086]. Thirty-two outermost uranium atom electrons are included in the valence shell (RECP for valence configuration $5s^25p^65d^{10}6s^26p^66d^15f^37s^2$). For comparison, the large-core RECP MT78 was used ($5s$, $5p$, and $5d$ electrons are included in the core).

The LCAO calculations [1085] were made for the cubic uranium mononitride UN (rock salt structure, two atoms per unit cell, space group $Fm\bar{3}m$; Fig. 12.2a), cubic uranium dinitride UN_2 (fluorite structure, three atoms per unit cell, space group $Fm\bar{3}m$; Fig. 12.2c), and a more complicated U_2N_3 crystal (5 atoms per unit cell, hexagonal structure with the space group $P\bar{3}m1$; Fig. 12.2b): the three nitrogen atoms split into the symmetry-nonequivalent groups of one and two atoms.

Two computer codes allowing the LCAO calculations of periodic systems were used: Gaussian03 [102] and Crystal09 [953]. The Monkhorst–Pack scheme [85] for $16 \times 16 \times 16$ k -point mesh in the Brillouin zone (BZ) was applied. It was found that both codes give close results if the direct lattice summation is done

Table 12.5 The results of LCAO calculations for UN crystal. The energy per unit cell E_{tot} and the U atom energy E_U are given in a.u., the cohesive energy E_c in eV, and the lattice constant in Å and the bulk modulus B in GPa. The experimental values are given in brackets in the first column. The U-atom spin-density SD is given in μ_B

Property	MT78	MT60	SK60
a (4.89)	5.17	4.78	4.80
E_{tot}	-106.5218	-531.0228	-531.9898
E_U	-51.5970	-475.9572	-476.9186
E_c (13.6)	9.6	13.4	13.6
B (194)	167.2	291.6	276.9
Q_U	1.63	1.55	1.58
SD	3.18	1.18	1.06
Population, e			
U s	2.05	4.20	4.04
p	5.98	12.03	12.15
d	1.11	11.96	11.96
f	3.23	2.26	2.27
N s	3.89	3.87	3.87
p	4.72	4.58	4.64
d	0.02	0.10	0.07

up to 50 a.u. in Gaussian03 and the tolerances 8 8 8 8 16 are used in Crystal09 for the Coulomb and exchange integrals calculations. The results of Gaussian03 and Crystal09 codes application to the UN crystal in DFT calculation (the PW91 exchange-correlation functional [342]) were compared in [1085]. For the U atom, RECP SC60 and the corresponding basis set with the removed diffuse functions were used. For the nitrogen atom, all-electron basis set $6 - 311 + +G(2d, 2p)$ was chosen, and the diffuse Gaussian function with the orbital exponent 0.0639 was removed. For the UN lattice parameter $a = 4.88\text{\AA}$ the total energy per unit cell of is -531.9863 a.u. (Crystal09) and -531.9873 a.u. (Gaussian03). The Mulliken atomic populations and the optimized lattice constant value are also close. In the further discussion, the results of LCAO calculations by Crystal09 code for bulk solids are used as this code takes into account the point symmetry in the direct lattice and BZ summations. In the Gaussian03 code, the crystal point symmetry is not taken into account so that the calculations are essentially more time consuming. The cohesive energy calculation requires free atom energy values for the U and N atoms. As the free atom BS includes diffuse GTF's, the atomic energies were obtained by the Gaussian03 code. In Table 12.5, the results of the bulk UN crystal calculation are presented for the three different RECPs mentioned. As is seen from this Table, the choice of RECP SK60 is preferable as it gives the best agreement for the experimentally known properties of UN crystal. The calculated U atom charge Q_U is close to +1.6 in all the calculations, while the populations of the U atom d and f orbitals are sensitive to RECP choice. However, the spin-density $SD = 1.06 \mu_B$ is the closest to the experimental value $0.85 \mu_B$ [1072] for RECP SK60.

Table 12.6 The results of UN crystal calculations with the RECP SK60 (all the figures are given in the same units as in Table 12.5)

Property	UHF	PW91	PBE	B3PW	PBE0
a (4.89)	4.84	4.80	4.80	4.79	4.78
E_c (13.6)	4.30	13.6	13.7	11.6	11.6
Q_U	1.89	1.58	1.57	1.68	1.69
SD	1.29	1.06	1.06	1.08	1.09
Population, e					
U s	4.03	4.04	4.04	4.04	4.03
p	12.24	12.15	12.16	12.13	12.14
d	11.90	11.96	11.97	11.95	11.98
f	1.94	2.27	2.26	2.20	2.16
N s	3.89	3.87	3.87	3.88	3.88
p	4.93	4.64	4.64	4.73	4.74
d	0.06	0.07	0.06	0.07	0.07

Table 12.6 presents the results of calculations for the RECP SK60 and different choices of the Hamiltonian of the crystal: the unrestricted Hartree–Fock (UHF), the DFT (PW91, PBE), and the hybrid HF–DFT B3PW and PBE0.

From Table 12.6, one can see that the cohesive energy is significantly underestimated in UHF and hybrid HF–DFT calculations but is close to the experimental value in DFT calculations. In the latter, the results for two different exchange–correlation functionals are close. As for the lattice parameter a , the LCAO DFT value 4.80 Å is not too different from those obtained in other DFT calculations: 4.86 Å (plane wave (PW), RECP PAW [1081]), 4.82 Å (PW RECP US [1082]), 4.90 Å (all-electron calculation with the numerical AO [1074]), and 4.86 Å (FP LAPW [1084]).

Now, we are going to discuss DFT (PW91) LCAO results for the mononitride UN in comparison with those for the two other nitrides UN₂ and U₂N₃. Table 12.7 presents the calculated properties of UN, UN₂, and U₂N₃ crystals—the lattice parameters, the cohesive energy, and the bulk modulus. LCAO DFT (PW91) RECP SK60 results are compared with those obtained in DFT (PW91) calculations [1081], using the PW basis and two different RECP 78 potentials for uranium core electrons (projected augmented waves (PAW) and ultrasoft (US)).

For the UN crystal, we also give the results (SK60 opt.b.s) obtained with the U atom and N atom basis-set optimization during the crystalline calculation. The initial uncontracted GTFs exponents (U:0.287(s), 0.144(p), 0.204(d), 0.490(f), and N: 0.201(p)) correspond to the energy per unit cell $E = -531.98984$ a.u.. The optimized values of these exponents are 0.221(s), 0.120(p), 0.102(d), 0.423(f), and 0.185(p) and correspond to the energy per unit cell $E = -532.01277$ a.u. The optimization of the basis set was done by both the Powell and the Hooke–Jeeves methods [1087]; the optimized exponent values are practically the same in both methods. Analyzing the results given in Table 12.7, one can make the following conclusions. The use of the same U atom BS with removed diffuse exponents for all the three crystals gives calculated properties in reasonable agreement with the

Table 12.7 Comparison of the lattice parameters a, c (Å); the cohesive energy E_c (eV); and the bulk modulus B (GPa) obtained in DFT PW (PAW, US [1081]) and LCAO (SK60) calculations with the exchange-correlation potential PW91 (The experimental values are given in bold)

Property	UN				U ₂ N ₃			UN ₂		
	PAW	US	SK60	SK60 opt.b.s	PAW	US	SK60	PAW	US	SK60
a, c	4.86	4.95	4.80	4.83	3.65,5.80	3.74,5.72	3.66,5.60	5.26	5.26	5.26
Exp.	4.89				3.70, 5.82			5.30		
E_c	14.7	12.3	13.6	14.2	36.3	30.1	34.6	21.5	17.9	20.9
Exp.	13.6				—			—		
B	226	182	277	237	209	154	232	265	236	270
Exp.	194				—			—		

Table 12.8 Local properties of uranium nitride electronic-structure, PAW results—from [1081]

Property	UN	U ₂ N ₃	UN ₂	UN(opt.b.s)
O_U (LCAO)	1.58	2.29	2.78	1.16
Q_N (LCAO)	−1.58	−1.55, −1.46	−1.39	−0.58
Q_U (PAW)	1.66	2.08	2.48	
Q_N (PAW)	−1.66	−1.50, −1.34	−1.24	
SD	1.06	0.58	0.0	1.09
Population, e				
U	s	4.04	4.02	4.06
	p	12.15	11.97	11.88
	d	11.96	11.45	12.45
	f	2.27	2.27	2.45
N	s	3.87	3.90, 3.89	3.81
	p	4.64	4.58, 4.53	4.30
	d	0.07	0.07, 0.04	0.05

results obtained in the plane-wave calculations. The LCAO results agree better with the PW results in the calculations with the PAW effective core potential. The basis-set optimization in LCAO calculations improves the agreement of the lattice parameter and the bulk modulus of the UN crystal with the experimental data; the change of the cohesive energy due to BS optimization is small.

The LCAO approach is a natural way to study the chemical bonding in a crystal as it allows one to extend to the periodic systems the procedures of the chemical-bonding analysis developed in the quantum chemistry of molecules [1145]. In Table 12.8, we present the results of the Mulliken population analysis application to the three uranium nitrides under consideration: the atomic charges of the U and N atoms (Q_U and Q_N), the spin density (SD) on the U atom, and the Mulliken populations of the atomic orbitals. For comparison, the Bader effective atomic charges are given, calculated in [1081] using the PAW RECP78 and PW basis set. As is seen from Table 12.8, the calculated atomic effective charges Q_U differ from the formal ionic charges +3, +4.5 and +6 in UN, U₂N₃, and UN₂ crystals, respectively. The mixed metallic-covalent chemical bonding is found both in LCAO and PW calculations of the UN and U₂N₃ crystals, in agreement with the discussions in the previous theoretical and experimental studies of the UN crystal. The UN₂ crystal has

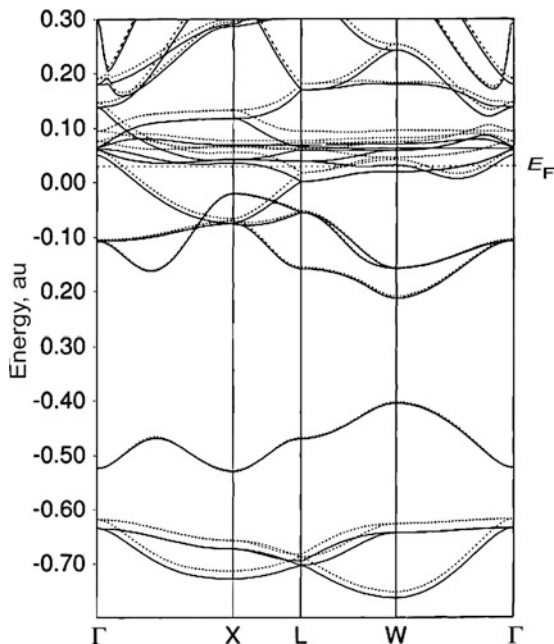
a semiconducting nature, in agreement with the results of all-electron calculations [1074]. LCAO results for the changes in the effective charges as a function of the decreasing U:N ratio (from UN to UN₂) confirm the conclusion [1081] that the uranium charge increases while the nitrogen charge decreases. However, the Mulliken atomic charges for the optimized BS give more covalent chemical bonding in the UN crystal, as the optimization increases the basis delocalization (see the discussion of Table 12.7). At the same time, the SD values demonstrate small changes with BS optimization. The results for the AO populations (which are not found in the Bader analysis) allow one to analyze the role of different U atom orbitals in chemical bonding when using RECP SK60 for the valence configuration $5s^2 5p^6 5d^{10} 6s^2 6p^6 6d^1 5f^3 7s^2$. As is seen from Table 12.8, the sum of $5s$ and $6s$ orbital populations is close to 4 in all the three crystals demonstrating their small participation in the chemical bonding. The $5f$ orbital population is close in UN and U₂N₃ crystals, but in the UN₂ crystal, $5f$ -electrons are more delocalized due to a high value of the formal U valence. From the UPS and XPS investigations of the core and valence levels of UN, 2.2 ± 0.5 electrons in the $5f$ -band near the Fermi level were derived [1072]. This result agrees with our LCAO (2.27) and FP LAPW [1084] (2.17) values for $5f$ -populations. It is seen that the change of the local atomic arrangement decreases p and d orbital populations. This means a larger participation of these orbitals in the chemical bonding with the increase of the formal U valence.

Figure 12.3 shows the upper part of valence and the lower part of the conduction energy bands for UN crystal (LCAO DFT-PW91 calculations with RECP SK60, the total spin projection $S_z = 1/2$). The states of the two lowest three times degenerated and nondegenerate subbands are formed by the U(p) and U(s) + N(s) atomic orbitals, respectively. The three times degenerated band around the energy value -0.10 a.u. is the mixed U(f) + N(p) band; the nondegenerate occupied band near the Fermi level is formed by U(f) states. The unpaired electron occupies the higher states of the three times degenerated U(d) band near the Fermi level. As seen from Tables 12.5 and 12.8, the SD value in the ground state of the metallic UN and U₂N₃ crystals is close to 1 in the calculations with RECP 60. This result differs from that found in [1076]: for different RECP's 78 used in [1076], the ground state with the spin projection $3/2$ has proved to be more favorable (the three f -electrons with the parallel spins occupy the states near the Fermi level). Figure 12.3 demonstrates that the use of RECP SK60 moves the nondegenerate U(f) band down changing the electron occupation of the band states near the Fermi level and the SD on the U atom. RECP SK60 results agree better with the experimental conclusion [1072] that the U atom in UN crystal has a moment of $0.75 \mu_B$.

The UN crystal is a rather complicated system because it is characterized by a mixed metal-covalent chemical bonding. The metallic part (U_{5f} states near the Fermi level) is better described by delocalized basis of the plane waves (PW), whereas the covalent part (U_{5f}-N_{2p} hybridization) by the LCAO basis set. The results of both approaches to UN are compared in [1088].

The LCAO part of calculations [1088] was performed as it was described in the previous subsection. In the PW part of calculations [1088], the VASP code

Fig. 12.3 Energy bands of the UN crystal (LCAO DFT/PWGGA calculations, RECP SK60) the energies are given in a.u. and the solid and dotted lines correspond to the states with spin-up and spin-down, respectively



[954] was applied with the projector-augmented-wave (PAW) pseudopotentials of the U and N atoms. The U atom PAW78 pseudopotential with a large-U-core RECP (78 core electrons, 14 valence electrons) is the same as in the previous VASP calculations on the UN [1080, 1081] containing the closed-shell configuration $6s^2 6p^6 5f^2 6d^2 7s^2$, while the U ground state possesses an open-shell configuration known as $5f^3 6d^1 7s^2$.²⁵ Unlike the calculations, [1080, 1081] two different exchange-correlation functionals and a very high accuracy in both the $\mathbf{k}$ -point mesh and the cutoff energy were used in [1088]. Both LCAO and PW spin-polarized (FM) bulk calculations were performed for the cubic crystalline structure of UN.

The conclusion could be drawn from Table 12.9 that the two DFT functionals used give similar results close to the previous VASP calculations [1080, 1081] performed with a smaller $\mathbf{k}$ -point mesh and lower cutoff energy. A comparison of Tables 12.6 and 12.9 demonstrates a qualitative correlation of the properties calculated using the LCAO (RECP 60) and the PW (RECP 78) methods, except for the bulk modulus which is noticeably overestimated in LCAO calculations compared with the experimental value. The analysis of the band structures for the UN bulk (presented in Fig. 12.4a and b) calculated by LCAO and PW methods using the same PW91 Hamiltonian demonstrates even detailed quantitative correlation, especially below the Fermi level, in agreement with the experiment [1089] and the previous DOS analysis performed in earlier PW VASP calculations [1081]. The results of the comparative LCAO and PW calculations [1088] on the UN (001) surface are discussed in the next section.

Table 12.9 The results of PW calculations [1088] for the UN bulk and their comparison with previously published data. See caption of Table 12.5 for explanation

Property	PW91	PBE	PW91-PAW [1080]	PBE-AE-LAPW [1083, 1084]
a_0 (4.886)	4.868	4.867	4.864	4.886
E_c (13.6)	14.79	14.57	14.7	13.4
$B(194)$	227	224	226	209
Q_U	1.69	1.69	1.61	—
SD	1.15	1.19	1.05	1.25

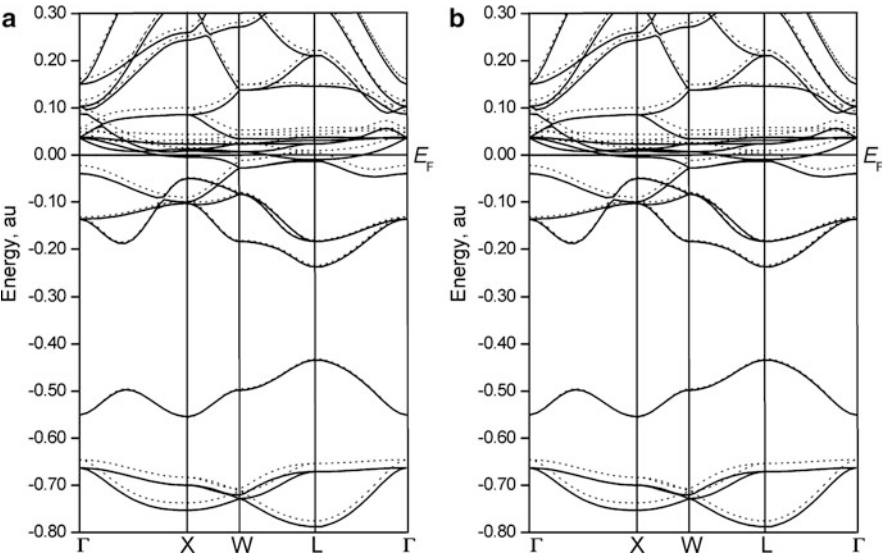


Fig. 12.4 The energy bands of UN crystal constructed for (a) LCAO PW91 (RECP 60) Hamiltonian and (b) PW PW91 (RECP 78) Hamiltonian. The energies are given in a.u., and the solid and dotted lines correspond to the states with spin-up and spin-down, respectively

12.2 Surface and Point-Defect Modeling in Uranium Nitrides

12.2.1 UN (001) Surface Calculations

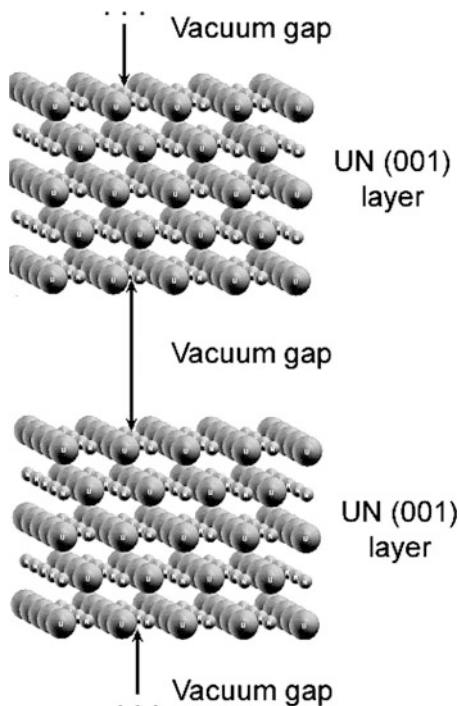
As we saw in Chap. 11, LCAO and PW surface calculations use single (2D) and repeated (3D) slab models, respectively. LCAO calculations do not require any artificial translation of the slab along the normal to the surface direction—something that is done in PW calculations to restore 3D periodicity. However, the use of atom-centered Gaussian BS faces in LCAO calculations is a rather serious problem known as the basis-set superposition error (BSSE). The problem is that in a system

comprising interacting fragments A and B, the fact that the basis sets on A and B are practically always incomplete means that the fragment energy of A has necessarily to be improved by the basis functions on B, irrespective of whether there is any genuine binding interaction in the AB system or not. The improvement in the fragment energies lowers the energy of the combined AB system. The BSSE is an ever-present phenomenon and accurate calculations should always include the BSSE analysis. A subject of particular concern is the binding energy of molecules adsorbed on the surfaces or the calculation of defect-formation energies [1145]. The approach most commonly used to estimate the BSSE effect is the counterpoise correction [451]: the separated fragment energies are not computed in the individual fragment basis sets but in the total basis set for the system including “ghost basis functions” for the fragment that is not present. These energies are then used to define the counterpoise-corrected (CPC) interaction energy. In the bulk crystal the AO basis of a given atom is extended by AOs centered on atoms in the neighboring unit cells. However, in the slab calculations, this is not true for surface atoms. This may lead to an underestimation of the slab energy and, as a consequence, to an overestimation of the surface energy. Moreover, the AO used in the crystal and slab calculation may not be sufficiently diffused to correctly reproduce the electronic-density distribution tail in the vacuum outside the surface. The corresponding corrections are similar to those arising for bulk solids and molecules. A simple and physically reasonable way to introduce the CPC interaction for the slab model of a surface (bare, reduced, relaxed) was suggested in [1090] and includes the addition of one and two extra layers of ghost atoms on both slab surfaces. The fixed ghost atoms are placed in their bulk positions, thus forming crystallographic planes next to the surface atomic planes. The additional Gaussians are centered on the ghost atoms and called an extra-layer basis set (ELBS). This approach was applied in [1090] in a study of water adsorption on SrTiO_3 (001) surface. The geometric structure of the slabs was reoptimized, by fixing the positions of the ghost atoms. It was found that the addition of the first ELBS introduces noticeable changes into the calculated properties, whereas the second ELBS has no further effect. In particular, the BSSE correction reduces the surface energy of cubic semiconducting perovskites and decreases the water adsorption energy.

For a metallic UN crystal, the large electron delocalization may increase the influence of the BSSE on the calculated surface energies and surface relaxation. This was demonstrated in [1088]. For DFT–PW surface calculations, 3D symmetric slabs consisting of 3–11 atomic layers separated by vacuum gaps of up to 15 empty layers were used (see Fig. 12.5). This interslab distance is large enough to exclude any interaction between the neighboring 2D slabs and to allow one to compare the 2D LCAO and 3D PW results.

In the PW surface calculations, only the PW91 Hamiltonian was used, since a comparison between the results of the PW91 and PBE calculations on the UN bulk (Table 12.9) does not show any noticeable differences. The Monkhorst–Pack scheme for the $8 \times 8 \times 1$ $\mathbf{k}$ -point mesh was applied. The cutoff energy was chosen to be 520 eV, just as in the case of the bulk. All the calculations were performed for the spin-polarized (FM) surface states. An in-depth analysis was performed for the vertical displacements along the z -axis of both the surface and subsurface

Fig. 12.5 Side view of a five-layer 3D slab model of the UN (001) surface



atoms from their host lattice sites in the UN bulk (Table 12.10), the effective atomic charges (Table 12.11), the surface energies (Table 12.12), as well as the DOS obtained in the PW calculations (see Fig. 12.6). The surface energy of an n -layer slab was estimated from the standard basic relationship $E_{\text{surf}} = (E_n - nE_b)/(2S)$, where E_n is the total slab energy per primitive surface unit cell and S —its area, while E_b is the total energy per primitive bulk unit cell.

There is a good qualitative agreement between the structural relaxations for the LCAO with an extra-layer and the corresponding PW data (Table 12.10). First of all, in both methods, the atomic displacements have the same directions: the N atoms go outward from the surface, whereas the U atoms relax inward, to the slab center. This is a pattern typical of the rumpling observed on oxide surfaces, but the rumpling in the UN is considerably larger. One also observes substantially larger magnitudes of the surface U displacements than the N atoms, whereas subsurface atom relaxations are smaller.

There is also a good agreement of the effective atomic charges calculated in the LCAO and PW using two very different Methods—Mulliken and Bader population analysis (Table 12.11). These charges indicate a considerable U–N bond covalency in both the UN bulk and on the surface. The asymmetrical electron-charge redistribution on the U and N atoms is likely to be caused by atomic displacements from a crystalline 2D plane.

Table 12.10 The calculated atomic displacements $\Delta_Z(\text{\AA})$ on UN (001) obtained for different slabs and methods. The positive sign means an outward displacement from the slab center and *vice versa*

Atom	Method	Number of atomic planes in slab				
		3	5	7	9	11
Surface U	LCAO	−0.085	−0.095	−	−	−
	LCAO	−0.026	−0.046	−	−	−
	(extra layer added)					
Subsurface U	PW PW91	−0.041	−0.020	−0.050	−0.061	−0.057
	LCAO		−0.011	−	−	−
	LCAO		−0.001	−	−	−
	(extra layer added)					
	PW PW91		−0.018	−0.016	−0.013	−0.013
	LCAO	0.064	0.058	−	−	−
Surface N	LCAO	0.0496	0.025	−	−	−
	(extra layer added)					
	PW PW91	0.030	0.022	0.025	0.033	0.026
Subsurface N	LCAO		−0.002	−	−	−
	LCAO		0.014	−	−	−
	(extra layer added)					
	PW PW91		0.026	0.028	0.032	0.022

The surface energies are stabilized for slab thicknesses of around 5–7 layers, whereas the relaxation energy is more sensitive to the thickness (Table 12.12). Because of a lack of experimental results, the calculated values of the surface energy could be qualitatively compared only with 1.0–1.2 J/m² obtained recently for the UO₂(001) surface energy using quantum-mechanical calculations [1091].

As one can see, the surface energies of UN (001) and UO₂(001) are predicted to be similar. A qualitative agreement is observed between the UN(001) surface energies obtained in the LCAO calculations using an extra-layer and the PW calculations. The increase in the number of atomic layers in the UN(001) slab stabilizes the energy of the relaxed surface.

The total and projected DOS in the FM state obtained in the PW calculations [1088] are shown in Fig. 12.6. There is a small difference in the band shapes from the previous UN bulk calculation [1081] due to the much higher **k**-point mesh and cutoff energy used. A comparison of the bulk DOS (Fig. 12.6a) with the DOS for the projection of the surface U and N atoms (Fig. 12.6b) shows that the main changes take place in the shape of the unoccupied states above the Fermi level. In both cases, the mixed metallic-covalent chemical bonding occurs with the U_{5f} states at the Fermi level, which is in line with the previous experimental and theoretical studies.

The calculation [1088] is the first detailed study of the properties of the densely packed UN(001) surface. The results obtained by means of two substantially different DFT methods (LCAO and PW) demonstrate good agreement. These results have been used in the study of surface defects and processes, first of all, the UN surface oxidation. The latter is an important practical problem which needs to be solved when advanced nuclear fuel is developed.

Table 12.11 The effective atomic charges $q(e)$ on the UN (001) slab

Atom	Method	Number of atomic planes in slab				
		3	5	7	9	11
Surface U	LCAO	1.63	1.63	–	–	–
	LCAO	1.64	1.64	–	–	–
	(extra layer added)					
Subsurface U	PW PW91	1.65	1.66	1.72	1.67	1.65
	LCAO	–	1.51	–	–	–
	LCAO	–	1.55	–	–	–
	(extra layer added)					
	PW PW91	–	1.65	1.63	1.63	1.69
Middle U	LCAO	1.45	1.57	–	–	–
	LCAO	1.52	1.55	–	–	–
	(extra layer added)					
Surface N	PW PW91	1.62	1.67	1.72	1.65	1.62
	LCAO	–1.55	–1.55	–	–	–
	LCAO	–1.61	–1.60	–	–	–
	(extra layer added)					
	PW PW91	–1.64	–1.63	–1.64	–1.63	–1.67
Subsurface N	LCAO	–	–1.59	–	–	–
	LCAO	–	–1.57	–	–	–
	(extra layer added)					
	PW PW91	–	–1.67	–1.7	–1.64	–1.7
	LCAO	–1.61	–1.58	–	–	–
Middle N	LCAO	–1.61	–1.58	–	–	–
	(extra layer added)					
	PW PW91	–1.58	–1.57			
(mirror plane of slab)		–1.65	–1.7	–1.66	–1.62	–1.64

Table 12.12 Surface energies E_{surf} (J m^{-2}) and relaxation energies E_{rel} (eV) obtained for the UN(001) surface in LCAO and plane-wave calculations

Number of atomic planes in slab		3	5	7	9	11
Method	E_{surf} (unrelaxed)	2.20	2.29	2.28	2.11	–
	LCAO E_{surf} (relaxed)	2.06	2.13	–	–	–
	E_{rel}	0.203	0.230	–	–	–
LCAO	E_{surf} (unrelaxed)	1.68	1.45	–	–	–
	(extra layer added) E_{surf} (relaxed)	1.430	1.38	–	–	–
	E_{rel}	0.359	0.121	–	–	–
Plane waves	E_{surf} (unrelaxed)	1.81	1.87	1.84	1.86	1.90
	PW91 E_{surf} (relaxed)	1.70	1.69	1.70	1.70	1.69
	E_{rel}	0.156	0.258	0.210	0.239	0.305

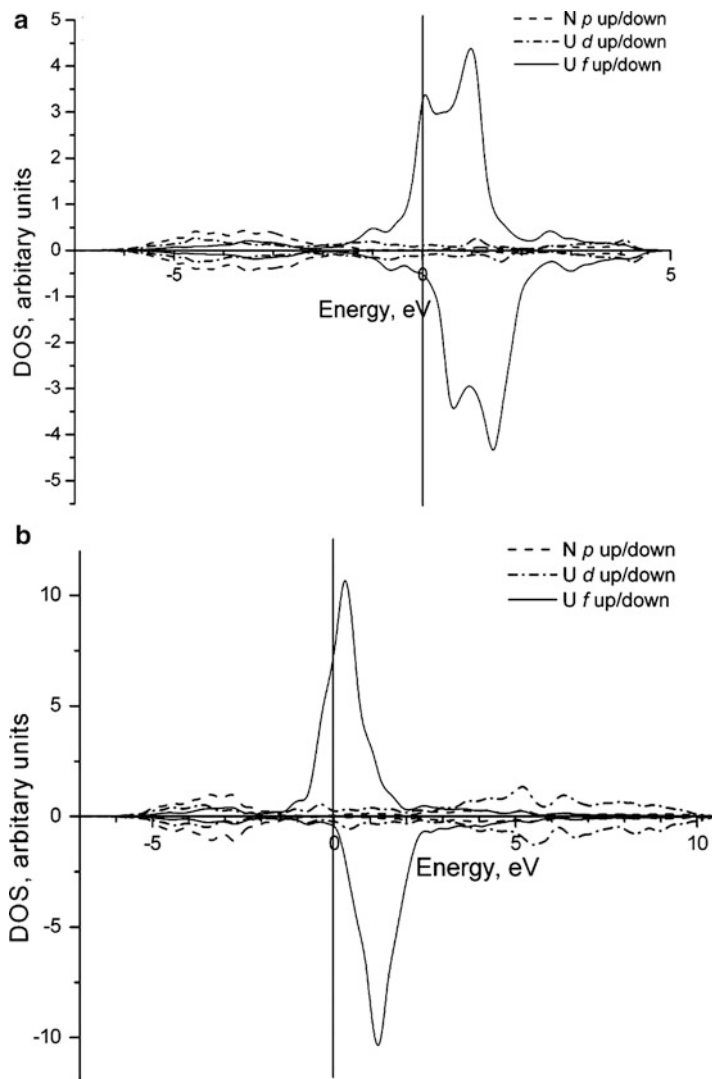
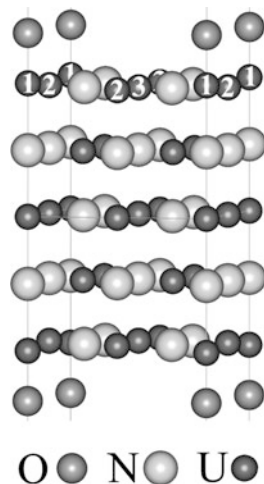


Fig. 12.6 The projected DOS for the bulk (a) and the perfect UN (001) surface (b) in FM states

12.2.2 *First-Principles Calculation of Point Defects in Bulk Uranium Nitride and on (001) Surface*

The first-principles plane-wave supercell calculations of oxygen impurities in the bulk UN crystal were performed in [1102]. The oxygen atom was placed either in an interstitial tetrahedral position or as a substitution for the host N ion. In the latter case, O perfectly fits into the N site producing no lattice distortion. Such oxygen

Fig. 12.7 A model of two-sided periodic adsorption of O atoms (0.25 ML) atop the surface U cations. The numbers denote nonequivalent interfacial atoms



substitutional impurity only slightly affects the formation energies of the U and N vacancies nearby. In both interstitial and substitutional positions, the oxygen atom attracts additional electron density and transforms into a negatively charged ion. Oxygen incorporation into the preexisting N vacancy is energetically preferable to incorporating it into the interstitial position. The O impurities produce an additional peak at the low-energy side of the N contribution to the UN calculated DOS which could be used for the O identification by means of the UPS spectroscopy. The DOS calculated for the UN and a hypothetical isostructural UO were compared. Both O solution and incorporation energies are negative, indicating that O penetration into the UN fuel is energetically preferable; see also [1098]. The migration energy of the interstitial O ion is estimated as 2.8 eV.

A review of the recent first-principles simulations of surface properties and oxidation of nitride nuclear fuels is given in [1092].

We discuss here the results of the first-principles calculations [1095] of oxygen adsorption on the UN (001) surface. Both LCAO and PW DFT calculations were performed. Only the ferromagnetic UN ground state was considered in this study as the energetically most preferable state at low temperatures. We saw that the calculations of the UN bulk structure suggested that the magnetic moment on the U cation is close to $1 \mu_B$. Thus, for the five-layer slab used in [1095], the total magnetic moment of 2×2 2D supercell (containing 20 U cations and 20 N anions) was fixed at $20 \mu_B$.

To simulate O atom adsorption, the same 2×2 2D supercell model with a periodic adsorbate distribution was used. These supercells with the 2×2 extension of surface translation vectors correspond to the atomic O coverage of 0.25 ML. To reduce computational efforts, a symmetric two-sided arrangement of the oxygen adatoms was considered; see Fig. 12.7. Two configurations of atomic adsorption were simulated: O atop the surface U cation or the N anion (Fig. 12.7) with complete structural optimization. For the plane-wave PAW calculations on the O/UN(001)

Table 12.13 The calculated binding energy (E_{bind}), the distance between O and surface U cation ($d_{\text{O-U}}$), the effective atomic charges (q), and vertical (Δz) U and N displacements from the surface plane for the adatom position atop the surface U. The effective charges of U and N ions on the pure surface are equal to +1.63 e for the surface U cation and -1.55 e for the surface N anion in LCAO 5-layer slab calculations and +1.66 e for the surface U cation and -1.63 e for surface N anion in PAW 5-layer slab calculation [1088]

Method of calculation	E_{bind} (eV)	$q(\text{O})$ (e)	$q(\text{U1})$ (e)	$q(\text{U2})$ (e)	$q(\text{U3})$ (e)	$q(\text{N})$ (e)	$d_{\text{O-U}}$ (Å)	$\Delta z(\text{U1})$ (Å)	$\Delta z(\text{U2})$ (Å)	$\Delta z(\text{U3})$ (Å)	$\Delta z(\text{N})$ (Å)
LCAO ^a	8.3	-0.89	1.97	1.66	1.62	-1.56	1.87	+0.15 ^b	-0.07	-0.11	-0.04
PAW ^c	6.9	-1.04	1.96	1.86	1.83	-1.60	1.91	+0.135 ^b	-0.02	-0.04	-0.05

^a LCAO-PBE calculations performed with *CRYSTAL-2006* code
^b The positive sign corresponds to the atom displacement outward from the substrate
^c PAW-PW91 calculations performed with *VASP-4.6* code

Table 12.14 The calculated parameters for the O atom adsorption atop the surface N anion^a. See the caption and footnotes of Table 12.13 for explanation

Method of calculation	E_{bind} (eV)	$q(\text{O})$ (e)	$q(\text{N1})$ (e)	$q(\text{N2})$ (e)	$q(\text{N3})$ (e)	$q(\text{U})$ (e)	$d_{\text{O-N}}$ (Å)	$\Delta z(\text{N1})$ (Å)	$\Delta z(\text{N2})$ (Å)	$\Delta z(\text{N3})$ (Å)	$\Delta z(\text{U})$ (Å)
PAW	5.0	-1.20	-1.44	-1.56	-1.59	-1.56	2.19	-0.64	+0.065	+0.06	+0.10

^a The atomic positions of the U and N ions are reversed as compared to those shown in Fig. 12.7

interface using a 3D slab model, one should also check whether the vacuum gap of 38.8 Å used for a five-layer slab of uranium nitride is large enough for models additionally containing adsorbed O atoms from both sides.

The binding energy E_{bind} of the adsorbed oxygen O_{ads} was calculated with respect to the free O atom: $E_{\text{bind}} = 0.5(E_{\text{tot}}^{\text{UN}} + 2E_{\text{tot}}^{\text{O(triplet)}} - E_{\text{tot}}^{\text{O/UN}})$ where $E_{\text{tot}}^{\text{O/UN}}$ is the total energy of a fully relaxed O/UN (001) slab for the O_{ads} positions atop either the N or U surface ions, $2E_{\text{tot}}^{\text{O(triplet)}}$ and $E_{\text{tot}}^{\text{UN}}$ —the energies of an isolated O atom in the ground (triplet) state and of a pure relaxed slab. In the PAW calculations of the free O atom, a cubic box with the same periodicity as for the O/UN (001) and UN (001) 3D slabs was used. The factor 0.5 appears since the substrate is modeled by a slab with the two equivalent surfaces and O_{ads} is positioned symmetrically with respect to these surfaces. Due to a mixed metallic-covalent nature of the chemical bonding in UN, one expects a high affinity of O_{ads} toward the UN(001) substrate. The binding energy per O adatom is expected to be closer to that on regular O/Al(111) and (001) metallic interfaces (being 10 eV in calculations [1093]) than on semiconducting O/SrTiO₃(001) interfaces (with two possible SrO or TiO₂-terminations) (2eV in calculations [1094]). Indeed, the binding energies obtained in the VASP calculations of 6.9 and 5.0 eV per O adatom atop the surface U or N ions, respectively, are accompanied by the 0.9–1.2 e charge transfer from the surface toward the O adatom (Tables 12.13 and 12.14). The positively charged surface *U* cation goes outward to the adsorbed O atom, whereas in the O configuration atop the N anion, the latter is significantly displaced from the adsorbed O atom toward the slab center due to a mutual repulsion.

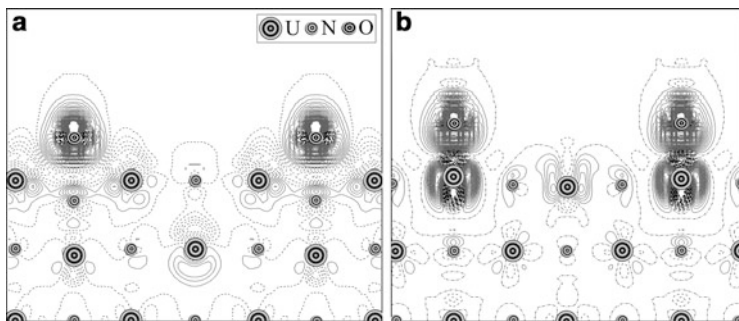


Fig. 12.8 The difference electron-density maps $\Delta\rho(r)$ (the total density of the interface minus the densities of the substrate and adsorbate with optimized interfacial geometry) for the O adatoms atop the surface: (a) N anions and (b) U cations on the UN(001) surface obtained using the results of the PAW calculations. The *solid and dashed isolines* correspond to positive and negative electron density, respectively. The isodensity increment is $0.003 \text{ e } \text{\AA}^{-3}$

The corresponding results of VASP (plane-wave basis) and CRYSTAL (LCAO basis) calculations based on the two very different methods demonstrate a good qualitative agreement for the O adatom properties atop the surface U ion (Table 12.13) in all the properties: the binding energies (3D slab models usually underestimate this parameter due to a weak repulsion between the adjacent polarized slabs), the atomic displacements, and even the effective charges (which are calculated using the very different Mulliken (LCAO) and Bader (PAW) procedures).

An analysis of the difference electron-charge redistributions for both configurations of O_{ads} (Fig. 12.8) confirms that the O adatom forms a strong chemical bonding with the surface U cation, which together could be considered as a one-site complex. In the case of the O adatom atop the surface N anion, this is an essentially multicenter adsorption complex involving four adjacent surface U ions. As follows from Table 12.13, these cations mostly contribute to the high O binding energy atop the N anion. Adsorption of O_{ads} atop the surface N or U ions on the UN(001) surface leads to appearance of the specific oxygen bands in the density of states (DOS) (Fig. 12.9) as compared to the DOS for a pure UN(001) surface (Fig. 12.6). For oxygen atop the surface U cation, the O_{2p} states overlap with the U_{6d} and with a well-pronounced tail of the U_{5f} states in the region of the N_{2p} valence band (-2 to -4 eV). This indicates once more a strong oxygen chemical bonding (chemisorption) on U, typical of metal surfaces. However, when O is located atop N, the U_{5f} contribution in this energy region diminishes, whereas the N_{2p} states are considerably pushed down to smaller energies, due to the N anion repulsion from negatively charged O adatom.

Summing up, the results obtained in [1095] for the oxygen interaction with the UN surfaces demonstrate a strong chemisorption typical of metallic surfaces and could serve as an important step toward understanding the initial stage of the oxidation mechanism. The excellent agreement of the results obtained when using two very different first-principles methods supports their reliability.

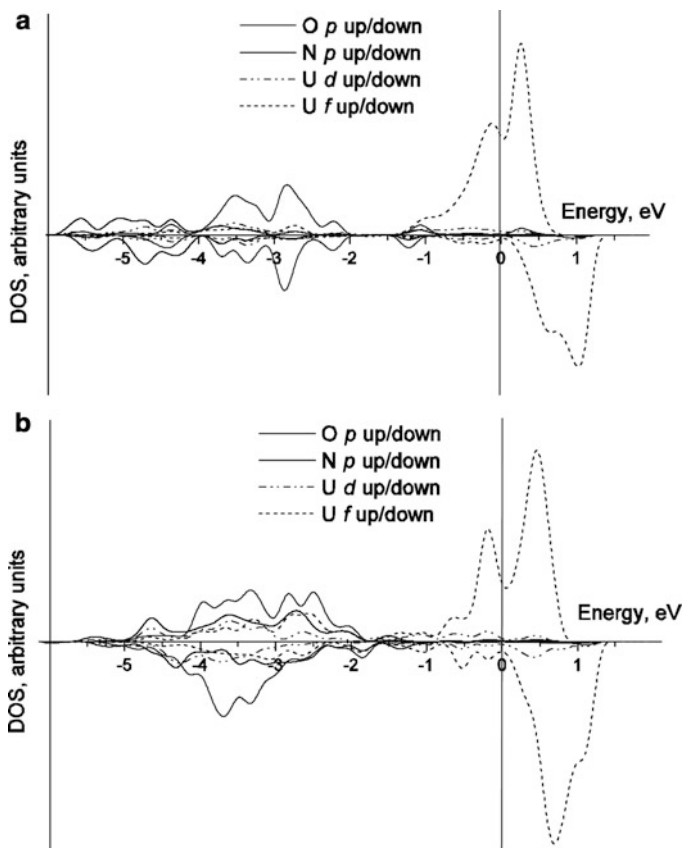


Fig. 12.9 The total and projected densities of states for the O atom adsorption atop the N anion (a) and the U cation (b) obtained using the results of PAW calculations. In the former, we consider the orbital projections of the N anion under the O atom and one of the four nearest neighboring U cations (Fig. 12.8a). Analogously, the lower plot presents the orbital projections of the U cation beneath the adatom and one of the four nearest N anions. The largest peaks were normalized to the same value, whereas the convolution of the individual energy levels was plotted using the Gaussian functions with a halfwidth 0.2 eV. “O” on the energy axis corresponds to the Fermi level

The study of the O_2 molecule dissociation and the diffusion path of O_{ads} on both perfect and defective UN(001) substrates was performed in [1096], and the aim of the study was to understand the atomistic mechanism of oxidation by means of substituting of the surface N ions for the O ions [1097, 1098].

Chapter 13

Symmetry and Modeling of BN, TiO₂, and SrTiO₃ Nanotubes

The commensurate line groups (also called monoperiodic groups) are symmetry groups of three-dimensional objects translationally periodic along a line—stereoregular polymers, nanotubes, and nanorods. The symmetry groups of nanoribbons and nanowires (75 rod groups) form a finite subset of an infinite number of line groups. The nanotube of the chirality (n_1, n_2) is obtained by folding the layer in a way that the chiral vector $\mathbf{R}$ becomes the circumference of the tube. The translational symmetry of the nanotube can exist for any arbitrary chirality (n_1, n_2) if the nanotube is obtained by folding the layer with square or hexagonal 2D lattices. The exploitation of the helical symmetry of nanotubes, usually quite high, permits one to drastically reduce the computational time and tackle large unit-cell nanotubes with an extended basis set. The first-principles LCAO calculations on BN, titania, and SrTiO₃ nanotubes performed using the hybrid Hartree–Fock/Kohn–Sham exchange–correlation functional (PBE0) allow one to predict their electronic and structural properties and estimate the nanotube strain energy.

13.1 Line Groups of One-Periodic Systems

13.1.1 Rod Groups as Subperiodic Subgroups of Space Groups

Seventy-five rod groups (RG) are known in crystallography as subperiodic subgroups of space groups (SG) [1103] and form the finite subset of an infinite number of line groups as the order q of rotation or screw axis can only be 1, 2, 3, 4, and 6. By analogy, with a space (three-periodic) and layer (two-periodic) groups, rod groups are factorized $RG = TF$ as an extension of the one-dimensional translations group T (invariant subgroup of RG) by the factor group $F = RG/T$. A subperiodic rod group RG can contain the following elements [1104]: translations $\mathbf{a}$ in one direction which by convention is designated as z-axis; a two-, three-, four-, or sixfold rotation or screw axis pointed in this direction; the rotation U around twofold

axes perpendicular to it; and reflection planes containing translation vector (vertical planes σ_v) and reflection planes perpendicular to it (horizontal planes σ_h). Every RG is in correspondence with some three-periodic space group SG: it is a subgroup of SG and has the same point symmetry group F . To obtain RG, it is sufficient to keep translations only in one direction in a related SG. The related RG and SG groups have the same international notations. Table 13.1 gives the correspondence between rod and space groups—their international notation, the number of the corresponding SG, and its Schoenflies symbol. This table can be compared with Table 11.1, where correspondence between three-dimensional two-periodic (DG) layer groups and three-dimensional three-periodic space groups (SG) is given. Screw axes in layer groups only can be the second-order axes, lying in the layer plane. Screw axes in rod groups are oriented along the translation direction and therefore can be axes of orders 2, 3, 4, and 6. One can find information about rod groups on the Bilbao Crystallographic Server [16]. These groups are specified by their number or by international symbols. The first symbol P (primitive) is the same for all rod groups as the translations are made along the principal symmetry axis, formally forming primitive one-periodic lattice. Then the information about symmetry elements is given. The screw axis of the order q has subscript p ($p = 0, 1, 2, \dots, q - 1$). The corresponding symmetry operations are rotations through $2\pi p/q$ about the z -axis. The reflection planes are denoted by m (mirror planes) and c (vertical glide planes containing the translation axis). The factor groups F of rod groups (called crystallography by crystal classes) are isomorphic to axial point groups C_q , D_q , S_{2q} , C_{qv} , C_{qh} , D_{qd} , and D_{qh} . For $q = 1, 2, 3, 4$, and 6, there are 31 different axial point groups, defining the crystal class of the related space and rod groups. The point groups D_1 , D_{1d} , and D_{1h} are isomorphic to the point groups C_2 , C_{2h} , and C_{2v} , respectively; the point groups C_{1h} and C_{1v} are isomorphic to the point group C_s . This isomorphism is used in crystallographic description of rod groups distributed over 27 crystal classes. The corresponding space groups are given in their Schoenflies notation in the second column in Table 13.1. As can be seen from Table 13.1, some rod groups are related to two different space groups as two possible RG settings can be chosen. For example, RG 46 (with the third-order rotation axis along z) is related to the space groups D_3^2 and D_3^1 when the second-order axis U is directed along the x - and y -coordinate axes, respectively. However, two different rod groups 15 ($Pmm2$) and 18 ($Pm2m$) are subgroups of the same SG 25. Whereas in RG 15 the second-order rotation axis is directed along the translation direction z , in RG 18 the second-order rotation axis is orthogonal to z . As in the latter case, this axis can be directed along both the x and y Cartesian axes; RG 18 has two settings— $P2mm$ and $Pm2m$, respectively. Seventy-five rod groups can be distributed over 13 families, as is shown in Table 13.2. Family 1 consists of rod groups belonging to classes C_q and containing rotations q or q_p , $p = 0, 1, \dots, q - 1$ (in international notations) around q -order ($q = 2, 3, 4, 6$) rotation or screw axis. Family 5 consists of rod groups belonging to classes D_q and containing rotations q or q_p around the q -order rotation or screw axis and rotations U . The symmorphic rod groups of classes S_{2q} , C_{qh} , C_{qv} , D_{qd} , and D_{qh} are related to families 2, 3, 6, 9, and 11, respectively. The remaining

Table 13.1 Rod groups (RG) as subperiodic subgroups of space groups (SG). The numbers of SG generating different RG or RG with different settings are given in brackets

RG		SG		RG		SG		RG		SG	
1	$P1$	1	C_1^1	26	$P4_3$	78	C_4^4	51	$P\bar{3}m1$	164	D_{3d}^3
2	$P\bar{1}$	2	C_i^1	27	$P\bar{4}$	81	S_4^1		$P\bar{3}1m$	162	D_{3d}^1
3	$P211$	(3)	C_2^1	28	$P4/m$	83	C_{4h}^1	52	$P\bar{3}c1$	165	D_{3d}^4
	$P121$	(3)	C_2^1								
4	$Pm11$	(6)	C_s^1	29	$P4_2/m$	84	C_{4h}^2		$P\bar{3}1c$	163	D_{3d}^2
	$P1m1$	(6)	C_s^1								
5	$P1c1$	(7)	C_s^2	30	$P422$	89	D_4^1	53	$P6$	168	C_6^1
	$Pc11$	(7)	C_s^2	31	$P4_122$	91	D_4^3	54	$P6_1$	169	C_6^2
6	$P12/m1$	(10)	C_{2h}^1	32	$P4_222$	93	D_4^5	55	$P6_2$	171	C_6^4
	$P2/m11$	(10)	C_{2h}^1	33	$P4_322$	95	D_4^7	56	$P6_3$	173	C_6^6
7	$P12/c1$	(13)	C_{2h}^4	34	$P4mm$	99	C_{4v}^1	57	$P6_4$	172	C_6^5
	$P2/c11$	(13)	C_{2h}^4	35	$P4_2cm$	101	C_{4v}^3	58	$P6_5$	170	C_6^3
8	$P112$	(3)	C_2^1		$P4_2mc$	105	C_{4v}^7	59	$P\bar{6}$	174	C_{3h}^1
				36	$P4cc$	103	C_{4v}^5	60	$P6/m$	175	C_{6h}^1
9	$P112_1$	4	C_2^2	37	$P\bar{4}2m$	111	D_{2d}^1	61	$P6_3/m$	176	C_{6h}^2
10	$P11m$	(6)	C_s^1		$P\bar{4}m2$	115	D_{2d}^5	62	$P622$	177	D_6^1
				38	$P\bar{4}2c$	112	D_{2d}^2	63	$P6_122$	178	D_6^2
11	$P112/m$	(10)	C_{2h}^1		$P\bar{4}c2$	116	D_{2d}^6	64	$P6_222$	180	D_6^4
12	$P112_1/m$	11	C_{2h}^2	39	$P4/mmm$	123	D_{4h}^1	65	$P6_322$	182	D_6^6
13	$P222$	16	D_2^1	40	$P4/mcc$	124	D_{4h}^2	66	$P6_422$	181	D_6^5
14	$P222_1$	17	D_2^2	41	$P4_2/mmc$	131	D_{4h}^9	67	$P6_522$	179	D_6^3
15	$Pmm2$	(25)	C_{2v}^1		$P4_2/mcm$	132	D_{4h}^{10}	68	$P6mm$	183	C_{6v}^1
16	$Pcc2$	27	C_{2v}^3	42	$P3$	143	C_3^1	69	$P6cc$	184	C_{6v}^2
17	$Pmc2_1$	(26)	C_{2v}^2	43	$P3_1$	144	C_3^2	70	$P6_3mc$	186	C_{6v}^4
	$Pcm2_1$	(26)	C_{2v}^2	44	$P3_2$	145	C_3^3		$P6_3cm$	185	C_{6v}^3
18	$Pm2m$	(25)	C_{2v}^1	45	$P\bar{3}$	147	C_{3i}^1	71	$P\bar{6}m2$	187	D_{3h}^1
	$P2mm$	(25)	C_{2v}^1	46	$P312$	149	D_3^1		$P\bar{6}2m$	189	D_{3h}^3
19	$P2cm$	(28)	C_{2v}^4		$P321$	150	D_3^2	72	$P\bar{6}c2$	188	D_{3h}^2
	$Pc2m$	(28)	C_{2v}^4	47	$P3_112$	151	D_3^3		$P\bar{6}2c$	190	D_{3h}^4
20	$Pmmm$	47	D_{2h}^1		$P3_121$	152	D_3^4	73	$P6/mmm$	191	D_{6h}^1
21	$Pccm$	49	D_{2h}^3	48	$P3_212$	153	D_3^5	74	$P6/mcc$	192	D_{6h}^2
22	$Pcmm$	(51)	D_{2h}^5		$P3_221$	154	D_3^6	75	$P6_3/mmc$	194	D_{6h}^4
	$Pmcm$	(51)	D_{2h}^5	49	$P3m1$	156	C_{3v}^1		$P6_3/mcm$	193	D_{6h}^3
23	$P4$	75	C_4^1		$P31m$	157	C_{3v}^2				
24	$P4_1$	76	C_4^2	50	$P3c1$	158	C_{3v}^3				
25	$P4_2$	77	C_4^3		$P31c$	159	C_{3v}^4				

6 families are formed by nonsymmorphic rod groups and include rotations around screw axes $(2q)_q$ with $q = 1, 2$, and 3 (families 4,8,13) or reflections in vertical glide planes (families 7,10,12). As can be seen from Table 13.2, rod groups 15 and 18 refer to families 6 (crystal class C_{2v}) and 11 (crystal class D_{1h}), respectively. In the next section, the one-periodic line groups are considered.

Table 13.2 Rod groups distribution over line group families (q —order of the rotation or screw axis), F—family number, N , N_c —number of groups and classes in family F

RGF	Class	Internat.		N , N_c	$q = 1$	$q = 2$	$q = 3$	$q = 4$	$q = 6$
		symbol	(odd q , even q)						
1	C_q	q, q_p		16	1(1)	8(112), 9(112 ₁)	42(3) 43(3 ₁) 44(3 ₂)	23(4), 24(4 ₁) 25(4 ₂), 26(4 ₃)	53(6), 54(6 ₁) 55(6 ₂), 56(6 ₃) 57(6 ₄), 58(6 ₅)
5	D_q	Classes		5	C_1	C_2	C_3	C_4	C_6
		$q2, q22$ q_q2, q_p22		16	3(211)	13(222), 14(222 ₁)	46(312) 47(3 ₁ 2) 48(3 ₂ 12)	30(422), 31(4 ₁ 22) 32(4 ₂ 22), 33(4 ₃ 22)	62(622), 63(6 ₁ 22) 64(6 ₂ 22), 65(6 ₃ 22) 66(6 ₄ 22), 67(6 ₅ 22)
2	S_{2q}	Classes		5	D_1	D_2	D_3	D_4	D_6
		$\overline{q}, \overline{2q}$		3	$2(\overline{1})$	$27(\overline{4})$	$45(\overline{3})$		
3	C_{qh} C_{2qh}	Classes		3	$S_2(C_i)$	S_4	$S_6(C_{3f})$		
		$\overline{2q}, q/m$ $(2q)_q/m$		5 3	10(11m)	11(112/ m) 12(112 ₁ / m)	59($\overline{6}$)	28(4/ m) 29(4 ₂ / m)	60(6/ m) 61(6 ₅ / m)

6	C_{qv}	Classes	5	C_{1h}	C_{2h}	C_{3h}	C_{4h}	C_{6h}
7	C_{qv}	qm, qmm	6	4($m11$)	15($mm2$)	49(3 $m1$)	34(4 mm)	68(6 mm)
8	C_{2qv}	qc, qcc	5	5($c11$)	16($cc2$)	50(3 $c1$)	36(4 cc)	69(6 cc)
		(2 q) $_qmc$	3		17($mc2_1$)		35(4 $_2mc$)	70(6 $_3mc$)
9	D_{qd}	Classes	5	C_{1v}	C_{2v}	C_{3v}	C_{4v}	C_{6v}
10	D_{qd}	$\overline{q}m, \overline{2q}2m$	2	6(2/ $m11$)	37($\overline{4}2m$)	51($\overline{3}m1$)		
		$\overline{q}c, \overline{2q}2c$	3	7(2/ $c11$)	38($\overline{4}2c$)	52($\overline{3}c1$)		
11	D_{qh}	Classes	3	D_{1d}	D_{2d}	D_{3d}		
12	D_{qh}	$\overline{2q}m2, q/mmm$	5	18(2 mm)	20(mmm)	71($\overline{6}m2$)	39(4/ mmm)	73(6/ mmm)
13	D_{2qh}	$2q2c, q/mcc$	5	19(2 cm)	21(ccm)	72(6 $c2$)	40(4/ mcc)	74(6/ mcc)
		(2 q) $_q/mmc$	3		22(mcm)		41(4 $_2/mmc$)	75(6 $_3/mmc$)
		Classes	5	D_{1h}	D_{2h}	D_{3h}	D_{4h}	D_{6h}
Total		75 rod groups, 31 crystal classes						

13.1.2 Line Groups

Commensurate line groups (LG) are the symmetry groups of three-dimensional objects translationally periodic along a line (also called one-periodic groups)—stereoregular polymers, nanotubes, and nanorods. The number of line groups is infinite as the translation axis can be the rotation or screw axis of any integer order q . The relevance of line groups for polymers was discussed by Vainstein [1105]. The derivation of commensurate line groups as the symmetry groups of stereoregular polymer molecules was presented in [1106]. The crystallographic factorization of the line group was used, which is given by

$$L = \sum_{i=1}^{n_p} (R_i | v_i) T \quad (13.1)$$

In (13.1), R_i and n_p are the operation and order of the isogonal point group P_I , respectively. For rod groups, the isogonal point group P_I coincides with the point group F isomorphic to the factor group RG/T . Improper translations v_i appear only in nonsymmorphic line groups. Such a factorization of the line group is the same as that of rod groups. However, in the former, the rotation axis order q is any positive integer number, in the latter $q = 1, 2, 3, 4, 5$, and 6. The orthogonal transformations of axial point groups P_I leave the z -axis invariant (rotations C_q around the z -axis, reflections σ_v in vertical planes) or reverse the direction of the z -axis (rotations U around the second-order axis perpendicular to the z -axis, reflections σ_h in horizontal planes). The former transformations are called the positive ones, the latter—the negative ones. As the product of negative elements is positive, the set of positive elements is either the whole group (positive group P_I^+) or a halving subgroup, when the group is called negative: $P_I^- = P_I^+ + p^- P_I^+$. It was shown that the isogonal point groups of equivalent line groups are necessarily conjugated by proper rotations which leave the z -axis invariant. The method of constructing of the physically distinct line groups [1106] is based on the fact that all isogonal point groups are either cyclic (C_q, S_{2q}) or the product of cyclic groups: $C_{qv} = C_q \wedge C_{1v}$; $C_{qh} = C_q \otimes C_{1h}$; $D_q = C_q \wedge D_1$; $D_{qd} = (C_q \wedge C_{1v}) \wedge D_1$; and $D_{qh} = (C_q \wedge C_{1v}) \wedge C_{1h}$. Line groups were classified into 13 infinite families which were introduced in the preceding subsection for rod groups.

Not being subgroups of space groups (unlike rod groups), line groups are a much wider class of symmetries. While rod groups describe only translationally periodical objects, line groups include symmetries of incommensurate structures. In the limit $q = \infty$, each family gives a continuous group P_∞ . These limiting groups correspond to the symmetry of linear molecules and also behave as the isogonal groups of incommensurate systems. Axial point groups P_I are discrete subgroups of the cylindrical point group P_∞ . When used to describe the symmetry of polymer molecules, line groups can also be factorized as a weak direct product of the intrinsic point symmetry P of monomer and the group of generalized translations Z , arranging these monomers along the direction of periodicity: $LG = ZP$; see [1107]

and references therein. The product of two subgroups is a group if and only if these subgroups commute, that is, $PZ = ZP$. The symmetry operations of polymers are defined as geometrical transformations leaving the compound unchanged. These operations occur in two different ways: as periodicity of the regular arrangement of monomers (comprise group Z) and as the intrinsic symmetry P of a single monomer. However, the intrinsic symmetry of the monomer P_n is the symmetry of the whole polymer only if it leaves simultaneously all the monomers unchanged, that is, if it is compatible with the periodical arrangement [1107]. This fact was used in [1108] for a line group classification: after an independent classification of all the possible arrangements and their symmetries, as well as of the symmetries of monomers, these two were combined in all possible compatible ways to get all the possible line groups. Such an approach allows one to consider the symmetry of both commensurate (one-periodic) and incommensurate (non-periodic) systems. Moreover, in such a way, one can directly obtain important information on the specific structure of line groups and can use it to explore many significant physical consequences. Table 13.3 presents rod groups in the form accepted for a line group classification. For the symmorphic RG, a crystallographic factorization $RG = TF$ coincides with that used for line groups ($RG = TP_I$). For nonsymmorphic RG, difference appears: compare Tables 13.2 and 13.3. Let us consider rod groups belonging to family 4. In the crystallographic factorization, these groups belong to classes C_{2qh} , $q = 1, 2$, and 3; see Table 13.2. However, the factor group F contains rotations around the screw axis of the order $(2q)_q$, that is, rotations around the translation axis are in fact rotohelical operations, including the rotation and improper translation by a half of the translation vector. The rod groups of family 4 can be factorized in such a way that the rotohelical operations are included in the cyclic group of the generalized translations Z (pure translations form the subgroup T of the group Z), and pure rotations are included in the point group P_n ; see 13.3. In this case, rod groups of family 4 are written in the form ZP , where $Z = T_q^1$ and $P_n = C_{nh}$. Next we consider the example of the rod groups of family 12, belonging to crystallographic class D_{qh} and containing reflections in the vertical glide planes; see Table 13.2. Now $Z = T'$ and contains all the pure translations and reflections in glide planes, while $P_n = C_{nh}$; see 13.3. Table 13.4 lists the line groups of thirteen families for any order q of the rotation or screw axis written in the form $L = ZP$ [1107]. The line group decomposition

$$L^{(F)} = \sum_{i=1}^{N_F} l_i^{(F)} L^{(1)} \quad (13.2)$$

contains the subgroup $L^{(1)}$ —a set of all rotohelical transformations, and in the case of the first family groups, $L^{(1)}$ is the line group itself. For families $F = 2, 3, \dots, 8$, it is a halving subgroup ($N_F = 2$); for the remaining families $F = 9, \dots, 13$, the first family subgroup $L^{(1)}$ is a subgroup of index four ($N_F = 4$). The coset representatives $l_i^{(F)}$ are given in Table 13.4 [1107]. We see from this table that some line groups can be given with different factorizations. Rotations around the z -axis

Table 13.3 Rod groups (international and factorized notation) listed by families F of line groups according to the order q of the principal axis of the isogonal group

F	q = 1	q = 2	q = 3	q = 4	q = 6
1	1 $L1 = TC_1$	8 $L2 = TC_2$ 9 $L2_1 = T_2C_1$	42 $L3 = TC_3$ 43 $L3_1 = T_3C_1$ 44 $L3_2 = T_3^2C_1$	23 $L4 = TC_4$ 24 $L4_1 = T_4C_1$ 25 $L4_2 = T_4C_2$ 26 $L4_3 = T_4^3C_1$	53 $L6 = TC_6$ 54 $L6_1 = T_6C_1$ 55 $L6_2 = T_6C_2$ 56 $L6_3 = T_6C_3$ 57 $L6_4 = T_6^2C_2$ 58 $L6_5 = T_6^5C_1$
2	2 $L\bar{1} = TS_2$	27 $L\bar{4} = TS_4$	45 $L\bar{3} = TS_6$		60 $L6/m = TC_{6h}$
3	10 $L\bar{2} = TC_{1h}$	11 $L2/m = T C_{2h}$	59 $L\bar{6} = TC_{3h}$	28 $L4/m = TC_{4h}$	61 $L6_3/m = T_6^3C_{3h}$
4		12 $L2_1/m = T_2C_{1h}$		29 $L4_2/m = T_4^3C_{2h}$	62 $L622 = TD_6$
5	3 $L12 = TD_1$	13 $L222 = TD_2$	46 $L32 = TD_3$	30 $L422 = TD_4$	63 $L6_122 = T_6D_1$
		14 $L2_122 = T_2C_1$	47 $L3_12 = T_3C_1$	31 $L4_122 = T_4D_1$	64 $L6_222 = T_6D_3$
			47 $L3_22 = T_3^2D_1$	32 $L4_222 = T_4D_2$	65 $L6_322 = T_6^1D_3$
				33 $L4_322 = T_4^1D_2$	66 $L6_422 = T_6^2D_2$
					67 $L6_522 = T_6^5D_1$
6	4 $L1m = TC_{1v}$	15 $L2mm = T C_{2v}$	49 $L3m = TC_{3v}$	34 $L4mm = TC_{4v}$	68 $L6mm = TC_{6v}$
7	5 $L1c = T^*C_1$	16 $L2cc = T^* C_2$	50 $L3c = T^*C_3$	36 $L4cc = T^*C_4$	69 $L6cc = T^*C_6$
8		17 $L2_1mc = T_2C_{1v}$		35 $L4_2mc = T_4C_{2v}$	70 $L6_3mc = T_6C_{3v}$
9	6 $L\bar{1}m = TD_{1d}$	37 $L\bar{4}2m = TD_{2d}$	51 $L\bar{3}m = TD_{3d}$		
10	7 $L\bar{1}c = T^*S_2$	38 $L\bar{4}2c = T^*S_4$	52 $L\bar{3}c = T^*S_6$		
11	18 $L\bar{2}2m = TD_{1h}$	20 $L2/mmm = T D_{2h}$	71 $L\bar{6}2m = T D_{3h}$	39 $L4/mmm = TD_{4h}$	73 $L6/mmm = T D_{6h}$
12	19 $L\bar{2}2c = T^*C_{1h}$	21 $L2/mcc = T^*C_{2h}$	72 $L\bar{6}2c = T^*C_{3h}$	40 $L4/mcc = T^*C_{4h}$	74 $L6/mcc = T^*C_{6h}$
13		22 $L2_1/mcm = T_2D_{1d}$		41 $L4_2/mcm = T_4D_{2d}$	75 $L6_3/mcm = T_6D_{3d}$

Table 13.4 Line groups. For each family, F different factorizations, the rotohelical subgroup $L^{(1)}$, generators, and the isogonal point group P_I are given in the first line. Below follow $N_F = |L^{(F)}|/|L^{(1)}|$, the international symbol (of commensurate groups only), family F^+ of the positive subgroup L^+ (for positive $F = F^+$), and the coset representatives $\ell_i^{(F)}$ for $i > 1$ of (13.2) (when $N_F = 4$, the first one gives L^+). T'_d and U_d are glide plane and horizontal axes bisecting vertical mirror planes, while $S_{2q} = C_{2q}\sigma_h$. For families 1 and 5, the order q of the isogonal principle axis is given by $Q = q/r$ (for commensurate groups); otherwise, q is infinite

F	Factorizations		$L^{(1)}$	Coset representatives		
N_F	q even	international	q odd	F^+	$\ell_i^{(F)}$	P_I
1		$T_Q \otimes C_n$		$T_Q \otimes C_n$	$(C_Q f), C_n$	C_q
1		L_{qp}		1		
2		$T \wedge S_{2q}$		$T \otimes C_q$	$(I a), S_{2q}$	S_{2q}
2	$\overline{L2q}$		$\overline{Lq}$	1	S_{2q}	
3		$T \wedge C_{qh}$		$T \otimes C_q$	$(I a), C_q, \sigma_h$	C_{qh}
2	Lq/m		$\overline{L2q}$	1	σ_h	
4		$T_{2q}^1 C_{qh} = T_{2q}^1 S_{2q}$		$T_{2q}^1 \otimes C_q$	$(C_{2q} a/2), C_q, \sigma_h$	C_{2qh}
2		$L(2q)_q/m$		1	σ_h	
5		$T_Q \wedge D_n$		$T_Q \otimes C_n$	$(C_Q f), C_n, U$	D_q
2	$Lq_p 22$		$Lq_p 2$	1	U	
6		$T \otimes C_{qv} = C_{qv} \wedge T'$		$T \otimes C_q$	$(I a), C_q, \sigma_v$	C_{qv}
2	$Lqmm$		Lqm	6	σ_v	
7		$C_q \wedge T'$		$T \otimes C_q$	$(\sigma_v a/2), C_q$	C_{qv}
2	$Lqcc$		Lqc	7	$(\sigma_v a/2)$	
8		$C_{qv} \wedge T_{2q}^1 = C_{qv} \wedge T'_d$		$T_{2q}^1 \otimes C_q$	$(C_{2q} a/2), C_q, \sigma_v$	C_{2qv}
2		$L(2q)_q mc$		8	σ_v	
9		$T \wedge D_{qd} = T' \wedge D_{qd}$		$T \otimes C_q$	$(I a), C_q, U_d, \sigma_v$	D_{qd}
4	$\overline{L2q} 2m$		$\overline{Lqm}$	6	σ_v, U_d, S_{2q}	
10		$T'S_{2q} = T'_d D_q$		$T \otimes C_q$	$(\sigma_v a/2), S_{2q}$	D_{qd}
4	$\overline{L2q} 2c$		$\overline{Lqc}$	7	$(\sigma_v a/2), S_{2q}, (U_d a/2)$	
11		$T \wedge D_{qh} = T'D_{qh}$		$T \otimes C_q$	$(I a), C_q, U, \sigma_v$	D_{qh}
4	Lq/mmm		$\overline{L2qm} 2$	7	σ_v, U, σ_h	
12		$T'C_{qh} = T'D_q$		$T \otimes C_q$	$(\sigma_v a/2), C_q, \sigma_h$	D_{qh}
4	Lq/mcc		$\overline{L2q} 2c$	7	$(\sigma_v a/2), U, (S_{2q} a/2)$	
13		$T_{2q}^1 D_{qh} = T_{2q}^1 D_{qd} =$ $T'_d D_{qh} = T'_d D_{qd}$		$T_{2q}^1 \otimes C_q$	$(C_{2q} a/2), C_q, U, \sigma_v$	D_{2qh}
4		$L(2q)_q/mmc$		8	σ_v, U, σ_h	

and translations along it commute, which implies that all the helical operations $(C_Q|f)$ (Q -is the rotation axis order, f is a partial translation) commute with pure rotations C_n around the z -axis, that is, rotations from the point group P_n . Therefore, any group P_n is compatible with any group $T_Q(f)$ for any Q . Their products $T_Q(f)C_n$ comprise first family line groups $L^{(1)}$ which are subgroups of all the other line groups. Similarly, all $T_Q(f)$ are compatible with groups D_n since $U(C_Q|f)' = (C_Q|f)^{-1}U$. The products $T_Q(f) \wedge D_n$ comprise the fifth family groups $L^{(5)}$. Other compatibility relations are as follows [1107]. Mirror planes of intrinsic symmetry can be retained only if Q is rational, that is, $Q = r/q$, where r and q are integers. It means that only commensurate helical groups allow a mirror

plane. These helical groups are $T(f = a)$ and $T_{2n}^1(f = a/2)$, where n is the order of the principal axis of a point group. On the other hand, the glide plane group T' is compatible with all axial point groups. The only requirement when a point group contains mirror planes or U -axis is that the glide plane should either coincide with them or bisect them, and different groups are obtained in these two cases. As a glide plane is commensurate, so are all the resulting groups. All the products of the point factor P and the generalized translation group Z define 11 remaining line group families, given in Table 13.4. Thus, one gets 13 infinite families of line groups. Each family includes all groups (with various parameters Q, f, n) with a fixed type of Z and P . Incommensurate line groups are either from the first or from the fifth family, while in all the other families, the generalized translation group is either the glide plane reflections group T' , the pure translation group T , or the zigzag group T_{2n}^1 . The products $L = ZP$ are weak direct, Z is a cyclic group, and the intersection of Z and P can only be identity element. If one or both subgroups are invariant, this product becomes semidirect (with the first factor invariant) or direct, respectively.

13.2 Nanotube Rolling Up from Two-Dimensional Lattices

13.2.1 General Procedure

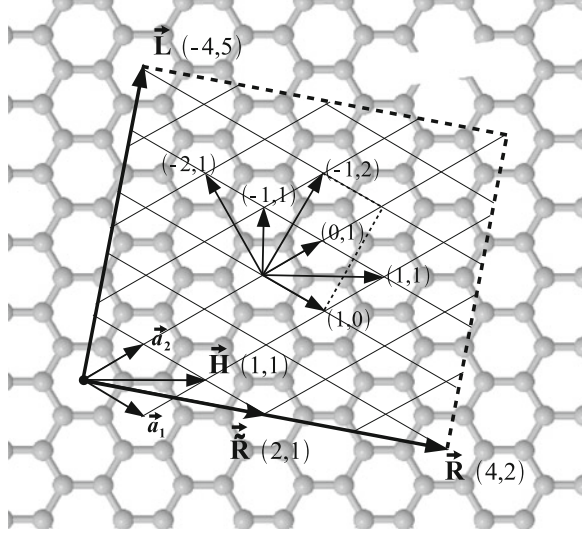
The simplest description of nanotube symmetry and structure is based on so-called layer folding. Let $\mathbf{a}$ and $\mathbf{b}$ be the primitive translation vectors $\mathbf{a}_1$ and $\mathbf{a}_2$ of the two-periodic (2D) lattice of the layer and γ —the angle between them. Layer folding means the construction of the cylindrical surfaces of nanotubes by rolling up 2D crystalline layers. To specify the symmetry of nanotubes as monoperoiodic (1D) systems, it is necessary to define the finite 1D translation vector $\mathbf{L} = l_1\mathbf{a} + l_2\mathbf{b}$ along the nanotube axis and normal to the chiral vector $\mathbf{R} = n_1\mathbf{a} + n_2\mathbf{b}$ (l_1, l_2, n_1 , and n_2 are integers). The nanotube of the chirality (n_1, n_2) is obtained by folding the layer in a way that the chiral vector $\mathbf{R}$ becomes circumference of the tube. The orthogonal vectors $\mathbf{R}$ and $\mathbf{L}$ are connected with the 2D lattice translation vectors $\mathbf{a}$ and $\mathbf{b}$ by the transformation

$$\begin{pmatrix} \mathbf{R} \\ \mathbf{L} \end{pmatrix} = \mathbf{Q} \begin{pmatrix} \mathbf{a} \\ \mathbf{b} \end{pmatrix} \quad (13.3)$$

The determinant $q = \begin{vmatrix} n_1 & n_2 \\ l_1 & l_2 \end{vmatrix}$ of the matrix $\mathbf{Q} = \begin{pmatrix} n_1 & n_2 \\ l_1 & l_2 \end{pmatrix}$ is equal to the number of 2D lattice points in the layer supercell formed by the chirality $\mathbf{R}$ and translation $\mathbf{L}$ vectors. The orthogonality relation $\mathbf{R}\mathbf{L} = 0$ can be written in the form

$$\frac{l_1}{l_2} = -\frac{n_2b^2 + n_1ab \cos \gamma}{n_1a^2 + n_2ab \cos \gamma} \quad (13.4)$$

Fig. 13.1 Chirality vectors of the nanotubes from graphene layer



where $a = |\mathbf{a}|$ and $b = |\mathbf{b}|$. If n is the greatest common divisor of n_1 and n_2 ($\tilde{n}_1 = n_1/n$, $\tilde{n}_2 = n_2/n$), one can introduce the reduced chirality vector $\tilde{\mathbf{R}}$ along the direction of the vector $\mathbf{R}$:

$$\tilde{\mathbf{R}} = \frac{1}{n} \mathbf{R}; \quad \begin{pmatrix} \tilde{\mathbf{R}} \\ \tilde{\mathbf{L}} \end{pmatrix} = \tilde{\mathbf{Q}} \begin{pmatrix} \mathbf{a} \\ \mathbf{b} \end{pmatrix}; \quad \tilde{\mathbf{Q}} = \begin{pmatrix} \tilde{n}_1 & \tilde{n}_2 \\ l_1 & l_2 \end{pmatrix}; \quad \tilde{q} = \det(\tilde{\mathbf{Q}}) \quad (13.5)$$

Nanotubes, being monoperiodic systems, have a line group symmetry $\mathbf{L} = Z\mathbf{P}$ [1109, 1110], where $\mathbf{P}$ is the point factor and $\mathbf{Z}$ is the generalized translation group. The point factor $\mathbf{P}$ is a subgroup of the axial point group $\mathbf{P}_I$ belonging to one of the axial symmetry point groups. The group $\mathbf{Z}$ is infinite and cyclic, describing either the glide plane reflections $T' = (\sigma_v | \frac{1}{2})$ or the screw axis rotations by $\frac{2\pi}{nq}$ (for $\tilde{q} > 1$) generated by helical operations $T_q^r = (C_q^r | \frac{1}{q})$ where $r = 0, 1, \dots, n-1$. For $n > 1$, pure rotations appear and form a subgroup of the point symmetry group $\mathbf{P}_I$. The smallest helical vector $\mathbf{H}$ is defined as $\mathbf{H} = h_1\mathbf{a} + h_2\mathbf{b} = \frac{r}{nq}\mathbf{R} + \frac{1}{q}\mathbf{L}$ and satisfies the following conditions: $\tilde{n}_1h_2 - \tilde{n}_2h_1 = 1$ and $h_1l_2 - h_2l_1 = r$. The projections of the helical vector $\mathbf{H}$ on the chiral vector $\mathbf{R}$ and translation vector $\mathbf{L}$ (Fig. 13.1) define the rotational and translational parts of the helical rotation T_q^r , respectively.

The symmetry of a nanotube is defined by the following: (a) the nanotube chirality (n_1, n_2) ; (b) translation vector components (l_1, l_2) found from the orthogonality relation, Eq. (13.4); and (c) the point symmetry of the rolled 2D lattice (see below). The orthogonality relation has different forms for different 2D lattices:

– Rectangular primitive ($\cos \gamma = 0$; $a \neq b$)

$$\frac{l_1}{l_2} = -\frac{n_2b^2}{n_1a^2}, \quad \text{or} \quad l_1n_1a^2 = -l_2n_2b^2; \quad (13.6a)$$

- Rectangular centered ($\cos \gamma \neq 0, \frac{1}{2}; a = b$)

$$\frac{l_1}{l_2} = -\frac{n_2 + n_1 \cos \gamma}{n_1 + n_2 \cos \gamma}; \quad (13.6b)$$

- Square ($\cos \gamma = 0; a = b$)

$$\frac{l_1}{l_2} = -\frac{n_2}{n_1} \quad \text{or} \quad l_1 n_1 + l_2 n_2 = 0; \quad (13.6c)$$

- Hexagonal ($\cos \gamma = \frac{1}{2}; a = b$)

$$\frac{l_1}{l_2} = -\frac{2n_2 + n_1}{2n_1 + n_2}. \quad (13.6d)$$

It is readily seen from Eq. (13.6) that the translational symmetry of the nanotube can exist for any arbitrary chirality (n_1, n_2) if the nanotube is obtained by folding the layer with square or hexagonal 2D lattices. However, there are restrictions on the possible chiralities for rectangular lattices: $(n, 0)$ and $(0, n)$ for rectangular primitive and $(-n, n)$ and (n, n) for rectangular centered ones.

The translations of the layer become rotohelical operations T_q^r on the nanotube, giving the first family subgroup $L^{(1)} = ZP(P = C_q)$ of the nanotube line group L . The latter has the same parameters for the ray of the nanotubes $(n_1, n_2) = n(\tilde{n}_1, \tilde{n}_2)$, differing by n .

Apart from the translational invariance, the layer groups have rotational symmetry generated by the rotations around the z-axis perpendicular to the layer. For rectangular, square, and hexagonal lattices, the order of these rotation axes is 2, 4, and 6, respectively. In addition, non-oblique 2D lattices have both vertical mirror and glide planes. In the layer groups, some of the 2D lattice symmetry operations are absent.

The symmetry operations matrices $G^{(3)} = (F^{(3)} | \mathbf{t}^{(2)})$, corresponding to the layer group, consist of orthogonal $F^{(3)}$ and translational $\mathbf{t}^{(2)}$ parts. Let the Cartesian axes x, y, and z be directed along the chiral vector $\mathbf{R}$, the nanotube translation vector $\mathbf{L}$, and the layer principal axis perpendicular to the layer, respectively.

During the folding procedure after the transformation described by Eq. (13.3) of the 2D lattice, the orthogonal symmetry operations survive if they do not change the z-coordinate (the layer is rolled up to the tube) and do not mix or interchange the x- and y-coordinates (chirality and translation vectors are assumed to be fixed). It means that after folding the layer, only those layer group symmetry operations survive which had the diagonal 2×2 submatrices:

$$F^Q = \begin{pmatrix} \pm 1 & 0 \\ 0 & \pm 1 \end{pmatrix}$$

$$E = \begin{pmatrix} 1 & 0 \\ 0 & 1 \end{pmatrix}, \quad U = \begin{pmatrix} -1 & 0 \\ 0 & -1 \end{pmatrix}, \quad \sigma_v = \begin{pmatrix} -1 & 0 \\ 0 & 1 \end{pmatrix}, \quad \sigma_h = \begin{pmatrix} 1 & 0 \\ 0 & -1 \end{pmatrix} \quad (13.7)$$

The transformations (13.7) include the rotation U by π around the second-order axis, normal to the tube, and reflections in planes, orthogonal to the 2D lattice plane and parallel to the tube axis, directed along the translation vector $\mathbf{L}(\sigma_v)$ or orthogonal to it (σ_h). In particular among the normal-to-layer rotation axes, only the twofold U -axis survive, being compatible with the monoprotic symmetry. Therefore, whenever the order of the principal axis of the layer is 2, 4, or 6, the symmetry of the nanotube is at least the fifth family line group $L^{(5)} = ZP(P = D_q)$.

The transformed translations $\mathbf{t}^Q$ can be written in the components of the vectors $\mathbf{R}$ and $\mathbf{L}$ as

$$\mathbf{t}^Q = (0 \ 0), \quad \left(\frac{1}{2n} \ 0\right), \quad \left(0 \ \frac{1}{2}\right), \quad \left(\frac{1}{2n} \ \frac{1}{2}\right) \quad (13.8)$$

where $n = 1$ for the reduced chirality vector $\tilde{\mathbf{R}}$, while $1/2$ in the second position produces the nonsymmorphic line groups containing the helical rotation $T_{2n}^1 = (C_{2n}^1 | \frac{1}{2})$ or the reflection in glide plane $T' = (\sigma_v | \frac{1}{2})$. The nanotube symmetry groups are formed by the point symmetry operations (13.7), and translations (13.8) survive the folding and combined in such a way that they form the line group $\mathbf{L} = ZP$.

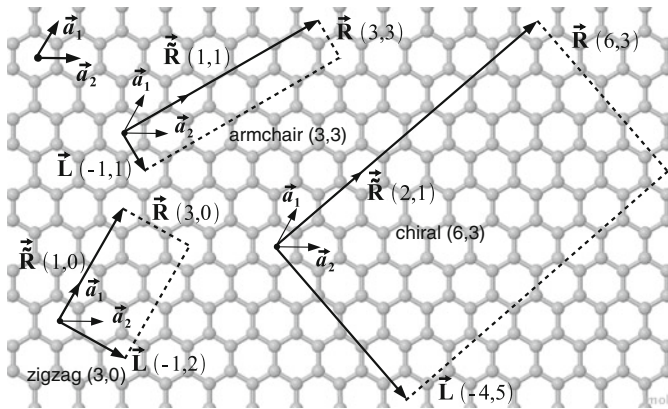
The procedure described can be applied for finding the nanotube symmetry if the symmetry of the layer group used for folding is known [1110]. A helical axis and pure rotations are always present in the line group of a nanotube, while mirror and glide planes appear only for special chiral vectors of rectangular, square, and hexagonal lattices. Table 13.5 presents the rolling up correspondence of the line and diprotic (layer) groups. For each family F of the line groups, the rotohelical subgroup $L^{(1)}$ and the isogonal group P_q^I (for irrational Q in families 1 and 5, q is infinite) are given in columns 2 and 3. The corresponding diprotic groups enumerated according to [1103] follow: for an arbitrary chiral vector, the rolling gives either the first or the fifth family line group (when the order of the orthogonal to the lattice plane axis is 2,4,6). The underlined diprotic groups (following after the corresponding special chiral vectors) give other line group families below. The corresponding special chiral vectors are the following: $\mathbf{a} = (n, 0)$, $\mathbf{b} = (0, n)$, $\mathbf{c} \in \{(n, 0), (0, n)\}$, $\mathbf{d} = (n, n)$, $\mathbf{e} = (-n, n)$, $\mathbf{f} \in \{(n, n), (-n, n)\}$, $\mathbf{g} \in \{(n, 0), (0, n), (-n, n)\}$, $\mathbf{h} \in \{(n, n), (-n, 2n), (-2n, n)\}$, and $\mathbf{i} \in \{(n, 0), (0, n), (-n, n), (n, n), (-n, 2n), (-2n, n)\}$.

13.2.2 Hexagonal Lattice

Different types of nanotubes can be rolled up from layers with a hexagonal plane lattice. We call them nanotubes with hexagonal morphology. Figure 13.2 shows the supercells of a graphene layer defining armchair (3,3), zigzag (3,0), and chiral (6,3) nanotubes.

Table 13.5 Rolling up correspondence of the line and diperiodic (layer) groups

F	$L^{(1)}$	P_q^I	Diperiodic groups
1	$T_Q C_n$	C_q	1,2,4,5,8,9,10, <u>11,12,13,14,15,16,17,18,27,28,29,30,31,32,33,34,35,36,65,66,67,68,69,70,71,72,74,78,79</u>
5	$T_Q C_n$	D_q	3,6,7,19,20,21,22, <u>23,24,25,26,37,38,39,40,41,42,43,44,45,46,47,48,49,50,51,52,53,54,55,56,57,58,59,60,61,62,63,64,73,75,76,77,80</u>
2	TC_q	S_{2q}	a: 17,33,34; b: 12,16,29,30
3	TC_q	C_{qh}	a: 11,14,15,27,31,32; b: 28
4	$T_{2q}^1 C_q$	C_{2qh}	e: 13,18,35; d: 36; h: 69,72,78; g: 70,71,79
6	TC_q	C_{qv}	a: 28; b: 11,14,15,27,31,32
7	TC_q	C_{qv}	a: 12,16,29,30; b: 17,33,34
8	$T_{2q}^1 C_q$	C_{2qv}	e: 36; d: 13,18,35; h: 70,71,79; g: 69,72,78
9	TC_q	D_{qd}	a: 42,45; b: 24,38,40
10	TC_q	D_{qd}	c: 25,39,43,44,56,60,62,63
11	TC_q	D_{qh}	c: 23,37,41,46,55,59,61,64
12	TC_q	D_{qh}	a: 24,38,40; b: 42,45
13	$T_{2q}^1 C_q$	D_{2qh}	f: 26,47,48,55,56,57,58,61,62,63,64; i: 77,80

**Fig. 13.2** Supercells of graphene layer defining armchair (3,3), zigzag (3,0), and chiral (6,3) nanotubes

The first reports on synthesis of carbon nanotubes [1113] were followed by extensive symmetry investigation [1107, 1114] of the nanotubes with hexagonal morphology. Equation (13.6d) ensures the orthogonality of the chiral and translation vectors. From Eq. (13.5), we find the matrix $\tilde{\mathbf{Q}}$, its determinant $\tilde{q}$, the components h_1 and h_2 of the smallest helical vector $\mathbf{H}$, and $r = h_1 l_2 - h_2 l_1$ for the special chiral vectors $\mathbf{R}$.

$$\mathbf{R}(n, n) : l_1/l_2 = -1; \quad \tilde{\mathbf{Q}} = \begin{pmatrix} 1 & 1 \\ -1 & 1 \end{pmatrix}; \quad \tilde{q} = 2; \quad \mathbf{H}(0, 1), \quad r = 1 \quad (13.9a)$$

$$\mathbf{R}(-n, n) : l_1/l_2 = 1; \quad \tilde{\mathbf{Q}} = \begin{pmatrix} -1 & 1 \\ -1 & -1 \end{pmatrix}; \quad \tilde{q} = 2; \quad \mathbf{H}(-1, 0), r = 1 \quad (13.9b)$$

$$\mathbf{R}(n, 0) : l_1/l_2 = -1/2; \quad \tilde{\mathbf{Q}} = \begin{pmatrix} 1 & 0 \\ -1 & 2 \end{pmatrix}; \quad \tilde{q} = 2; \quad \mathbf{H}(0, 1), r = 1 \quad (13.9c)$$

$$\mathbf{R}(-n, 2n) : l_1 = 1, l_2 = 0; \quad \tilde{\mathbf{Q}} = \begin{pmatrix} -1 & 2 \\ -1 & 0 \end{pmatrix}; \quad \tilde{q} = 2; \quad \mathbf{H}(-1, 1), r = 1 \quad (13.9d)$$

$$\mathbf{R}(-2n, n) : l_1 = 0, l_2 = -1; \quad \tilde{\mathbf{Q}} = \begin{pmatrix} -2 & 1 \\ 0 & -1 \end{pmatrix}; \quad \tilde{q} = 2; \quad \mathbf{H}(-1, 1), r = 1 \quad (13.9e)$$

As $\tilde{q} = 2$ for all the special chiral vectors, the roto-translational part of the corresponding line group is $T_{2n}^1 = (C_{2n}^1 | \frac{1}{2})$, while $q = n\tilde{q}$ and $L = T_{2n}^1 P_n$. For the general chiral vector $\mathbf{R}(n_1, n_2)$, ($n_1 \neq 0, n_2 \neq 0; n_2 \neq \pm n_1, -2n_1, -\frac{1}{2}n_1$), we have

$$\tilde{\mathbf{Q}} = \begin{pmatrix} \tilde{n}_1 & \tilde{n}_2 \\ -(2\tilde{n}_2 + \tilde{n}_1) & (2\tilde{n}_1 + \tilde{n}_2) \end{pmatrix}, \quad \tilde{q} = 2(\tilde{n}_1^2 + \tilde{n}_1\tilde{n}_2 + \tilde{n}_2^2); \quad \tilde{n}_1\tilde{n}_2 - \tilde{n}_2\tilde{n}_1 = 1; \\ (2\tilde{n}_1 + \tilde{n}_2)h_1 + (2\tilde{n}_2 + \tilde{n}_1)h_2 = r$$

In this case, the rotohelical operations are $T_q^r = (C_q^r | \frac{1}{q})$, $q = n\tilde{q}$ is the order of the screw axis, and $r = 0, 1, 2, \dots, q-1$.

Keeping in mind these results, let us analyze Table 13.5. The hexagonal lattice defines layer groups 65–80 (see Table 11.1 in Chap. 11). In groups 65–68 and 74, the order 3 axes are orthogonal to the lattice plane, and mirror planes are absent. Therefore, these groups belong to family one, and the tubes rolled up from the corresponding layers have the same symmetry for any chiral vector $\mathbf{R}(n_1, n_2)$. The tubes rolled up from layers with di-periodic groups 69, 72, 78, 70, 71, and 79 belong to families 4 and 8 depending on the setting of the special chiral vector relative to the mirror planes. In all these groups, the mirror planes that are orthogonal to the x- or y-axis appear. Finally, the tubes rolled up from the layers with di-periodic groups 77 and 80 belong to family 13: in these layer groups, there are mirror planes orthogonal both to the x- and y-axis.

13.2.3 Square Lattices

Perovskite SrTiO_3 and BaTiO_3 nanotubes are synthesized by a low-temperature hydrothermal reaction [1115]. These nanotubes have a square morphology, that is, can be rolled up from layers with a square plane lattice ($\cos \gamma = 0; a = b$) [1119]. From Eq. (13.6c), it follows that $l_1n_1 + l_2n_2 = 0$. Applying Eq. (13.5), we have

$$\mathbf{R}(n, 0) : l_1 = 0, l_2 = 1; \quad \tilde{\mathbf{Q}} = \begin{pmatrix} 1 & 0 \\ 0 & 1 \end{pmatrix}; \quad \tilde{q} = 1; \quad \mathbf{H}(0, 1), r = 0 \quad (13.10a)$$

$$\mathbf{R}(0, n) : l_1 = -1, l_2 = 0; \quad \tilde{\mathbf{Q}} = \begin{pmatrix} 0 & 1 \\ -1 & 0 \end{pmatrix}; \quad \tilde{q} = 1; \quad \mathbf{H}(-1, 0), r = 0 \quad (13.10b)$$

As in Eqs. (13.10a) and (13.10b) $r = 0$, no screw axis appears either for $\mathbf{R}(n, 0)$ or $\mathbf{R}(0, n)$ special chiral vectors.

$$\mathbf{R}(n, n) : l_1 = -1, l_2 = 1; \quad \tilde{\mathbf{Q}} = \begin{pmatrix} 1 & 1 \\ -1 & 1 \end{pmatrix}; \quad \tilde{q} = 2; \quad \mathbf{H}(0, 1), r = 1 \quad (13.10c)$$

$$\mathbf{R}(-n, n) : l_1 = -1, l_2 = -1; \quad \tilde{\mathbf{Q}} = \begin{pmatrix} -1 & 1 \\ -1 & -1 \end{pmatrix}; \quad \tilde{q} = 2; \quad \mathbf{H}(-1, 0), r = 1 \quad (13.10d)$$

As in Eqs. (13.10c) and (13.10d) $\tilde{q} = 2$, the rototranslational part of the corresponding line groups is $T_{2n}^1 = (C_{2n}^1 | \frac{1}{2})$, while $q = n\tilde{q} = 2n$ and $L = T_{2n}^1 P_n$. For the general chiral vector $\mathbf{R}(n_1, n_2)$, ($n_1 \neq 0, n_2 \neq 0; n_2 \neq \pm n_1$), we have

$$\tilde{\mathbf{Q}} = \begin{pmatrix} \tilde{n}_1 & \tilde{n}_2 \\ -\tilde{n}_2 & \tilde{n}_1 \end{pmatrix}, \quad \tilde{q} = \tilde{n}_1^2 + \tilde{n}_2^2; \quad \tilde{n}_1 h_2 - \tilde{n}_2 h_1 = 1; \quad \tilde{n}_1 h_1 + \tilde{n}_2 h_2 = r; \quad (13.10e)$$

$$h_1 = \frac{1}{\tilde{q}}(r\tilde{n}_1 - \tilde{n}_2); \quad h_2 = \frac{1}{\tilde{q}}(r\tilde{n}_2 + \tilde{n}_1)$$

In this case, the rotohelical operations are $T_q^r = (C_q^r | \frac{1}{q})$, $q = n\tilde{q}$ is the order of the screw axis, and $r = 0, 1, 2, \dots, q - 1$.

Now let us analyze Table 13.5 for layer groups 49–64 with a square lattice. In all these groups, the order four axis is orthogonal to the lattice plane. Therefore, the tubes with the general chiral vector $\mathbf{R}(n_1, n_2)$ belong to the fifth family. In groups 49–54, there are no mirror planes orthogonal to the lattice plane. Therefore, the line group of the corresponding nanotubes belong to the fifth family. As no screw axis appears for the tubes with the special chiral vectors $\mathbf{R}(n, 0)$ and $\mathbf{R}(0, n)$, see Eqs. (13.10a) and (13.10b), the corresponding line groups 56, 60, 62, and 63 and 55, 59, 61, and 64 are symmorphic and belong to families ten and eleven, respectively. These two sets of groups differ in the type of the mirror plane: in the former, the orthogonal to the x-axis plane is a glide plane; in the latter, this plane is a mirror plane. In layer groups 57 and 58, there are no mirror or glide planes orthogonal to the x-axis. The special chiral vectors $\mathbf{R}(n, n)$ and $\mathbf{R}(-n, n)$,

see Eqs. (13.10c) and (13.10d), generate tubes with line groups belonging to family 13 with a rotohelical tube axis of the order $q = 2n$.

13.2.4 Rectangular Lattices

The layers with rectangular lattices are used for inorganic TiO_2 nanotube modeling [1116–1118].

For the primitive rectangular lattice ($\cos \gamma = 0; a \neq b$), we have $l_1 n_1 a^2 = -l_2 n_2 b^2$; see Eq. (13.6a). For commensurate nanotubes, a/b has to be a rational number as it defines l_1/l_2 (l_1, l_2 are integers). It means that the nanotubes are commensurate only for the special chiral vectors.

$$\mathbf{R}(n, 0) : l_1 = 1, l_2 = 0; \quad \tilde{\mathbf{Q}} = \begin{pmatrix} 1 & 0 \\ 0 & 1 \end{pmatrix}; \quad \tilde{q} = 1; \quad \mathbf{H}(0, 1), r = 0 \quad (13.11a)$$

$$\mathbf{R}(0, n) : l_1 = 0, l_2 = 1; \quad \tilde{\mathbf{Q}} = \begin{pmatrix} 0 & 1 \\ -1 & 0 \end{pmatrix}; \quad \tilde{q} = 1; \quad \mathbf{H}(-1, 0), r = 0 \quad (13.11b)$$

It is seen that for a primitive rectangular lattice, the screw axis is absent ($r = 0$).

For the rectangular centered lattice ($\cos \gamma \neq 0, 0.5; a = b$), see Eq. (13.6b), we have

$$\frac{l_1}{l_2} = -\frac{n_2 + n_1 \cos \gamma}{n_1 + n_2 \cos \gamma};$$

The corresponding nanotubes are commensurate for the following special chiral vectors:

$$\mathbf{R}(n, n) : l_1 = -1, l_2 = 0; \quad \tilde{\mathbf{Q}} = \begin{pmatrix} 1 & 1 \\ -1 & 1 \end{pmatrix}; \quad \tilde{q} = 2; \quad \mathbf{H}(0, 1), r = 1 \quad (13.12a)$$

$$\mathbf{R}(-n, n) : l_1 = -1, l_2 = -1; \quad \tilde{\mathbf{Q}} = \begin{pmatrix} -1 & 1 \\ -1 & -1 \end{pmatrix}; \quad \tilde{q} = 2; \quad \mathbf{H}(-1, 0), r = 1 \quad (13.12b)$$

In this case, the rotohelical operations are $T_q^r = (C_q^r | \frac{1}{q})$, $q = 2n$ is the order of the screw axis, and $r = 0, 1, 2, \dots, q - 1$.

Now let us analyze Table 13.5 for layer groups 8–48 with rectangular primitive and centered lattices. In groups 8–10, there are no U -axis or mirror planes, and these groups generate nanotubes belonging to the first family. The twofold axis orthogonal to the layer plane appears in layer groups 19–22, so that the corresponding nanotube symmetry belongs to the fifth family. The line groups generated by the rolling vectors $\mathbf{R}(n, 0)$ and $\mathbf{R}(0, n)$ are both symmorphic (families 2,3,6,9) or contain a glide plane (families 7,9,12). The line groups generated by the rolling vectors $\mathbf{R}(n, n)$ and $\mathbf{R}(-n, n)$ are nonsymmorphic (families 4,8,13).

13.2.5 Symmetry of Double- and Multiwall Nanotubes

The symmetry groups of double-wall and multiwall nanotubes are considered in [1107, 1109, 1120]. The symmetry of SW NTs is described by line group $L = ZP$, which is a product of axial point group P and the infinite cyclic group Z of generalized translations (see Sect. 13.1.2). The latter consists of rotations by $2\pi r/q$ around the q -order screw axis, translations $(n/q)a$ (a denotes the translational period), or reflections in the glide plane $(\sigma_v|a/2)$. Here $n = G(n_1, n_2)$ is the greatest common divisor and (n_1, n_2) defines the chiral vector of SW NT.

The line symmetry group of a double-wall nanotube can be found as the intersection $L_2 = Z_2 P_2 = (L \cap L')$ of the symmetry groups L and L' of its single-wall constituents [1120]. The intersection $P_2 = (P \cap P')$ of the point groups is chosen independently of the generalized translational factor Z_2 [1109].

Let (n_1, n_2) and (n'_1, n'_2) define the chiral vectors of the single-wall constituents of a double-wall nanotube. Its axial point group $P_2 = C_N$ is the principal axis subgroup of the DW NT line group $\mathbf{L}_2$ with $N = G(n, n') = G(n_1, n_2, n'_1, n'_2)$. Only nanotubes composed exclusively of either (n, n) (armchair) or $(n, 0)$ (zigzag) SW constituents can have additional mirror or glide planes, as well as a rotoreflectional axis. The translational factor Z_2 is completely absent for incommensurate DW NT, that is, when the ratio a/a' is not rational [1109]. As an example, we can mention DW NT formed from the hexagonal SW NTs with different types of chirality, both armchair and zigzag, that is, $(n_1, n_1)@(n_2, 0)$, where the ratio $a/a' = \sqrt{3}$ (a, a' are lengths of the translation vectors of SW constituents).

The coaxial hexagonal DW NTs with $(n_1, n_1)@(n_2, n_2)$ and $(n_1, 0)@(n_2, 0)$ chiralities are commensurate: their translation period is the same as for the constituents— $\mathbf{L} = -\mathbf{a} + \mathbf{b}$ (nn chirality) and $\mathbf{L} = -\mathbf{a} + 2\mathbf{b}$ ($n0$ chirality)—as described by Eq. (13.6d). For the square lattice period of such, DW NTs is the same as for the constituents: $\mathbf{L} = \mathbf{a} - \mathbf{b}$ ((n, n) chirality) and $\mathbf{L} = \mathbf{b}$ ($(n, 0)$ chirality), as described by Eq. (13.6c). For the commensurate DW NT, the translational factor Z_2 contains rotations around the screw axis, common to both SW components. Two possibilities for periodic DW NTs have been considered in [1109]: (i) both n_1/N and n_2/N are odd— $\mathbf{L}_2$ contains the screw axis $(2N)_N$ and (ii) either one or both n_1/N and n_2/N are even— $\mathbf{L}_2$ contains the rotation axis of order the N . As an example of the first possibility, one has hexagonal DW NT $(6, 6)@(10, 10):N = 2$, $n_1/N = 3$, $n_2/N = 5$, and the screw axis 4_2 . For DW NT $(12, 0)@(18, 0)$, we have $N = 6$, $n_1/N = 2$, $n_2/N = 3$, and the rotation axis of order 6.

In the particular case of commensurate armchair $(n_1, n_1)@M(n_1, n_1)$ and zigzag $(n_1, 0)@M(n_1, 0)$ DW nanotubes with hexagonal morphology (i.e., $n_2 = Mn_1$), the symmetry group can be found from the results obtained in [1109] for the full symmetry of multiwall nanotubes. For armchair and zigzag DW NTs with odd M , the line symmetry groups are the same as for their SW constituents— $(2n)_n/m$ (family 4, point symmetry C_{2nh}) and $(2n)_nmc$ (family 8, point symmetry C_{2nv}), respectively. For an even M , the rotations about the screw axis of the order $2n$ are replaced by rotations around the pure rotation axis of the order n so that DW NT

line symmetry groups become n/m (family 3, point symmetry C_{nh}) and nm (family 6, point symmetry C_{nv}), for armchair and zigzag chiralities, respectively.

For each SW NT, the coordinate system can be chosen with its origin fixed in the initial nanosheet (slab) which the folding procedure has to be applied to. The normal to the slab plane passing through the origin can be defined as x -axis in the SW NT coordinate system. Because of the coaxiality, the two parameters completely determine the relative positions of SW constituents in DW NT: the angle φ and length Δz by which the outer tube is rotated around z and translated along z , respectively (in regard to the initial configuration with the coinciding x - and x' -axis of both shells) [1109, 1120]. Thus, the initial position of both SW constituents in DW NTs is characterized by $\varphi = 0$ and $\Delta z = 0$. In this case the maximum possible number of symmetry elements for both SW NTs coincides, and the symmetry of the initial DW NT structure is described by one of the line groups considered above. After atomic relaxation, the values of φ and Δz can differ from zero. Presumably, the rototranslational part of DW NT symmetry group (independent of the relative SW NT positions) is not changed after the relaxation. However, other common symmetry elements of SW NTs (second-order U -axis normal to the translation vector, reflection, and glide planes) can be lost. Thus, the total symmetry of DW NT is reduced. The symmetry of DW NT with hexagonal and square morphology is considered in more detail in next subsections dealing with BN, TiO_2 , and SrTiO_3 nanotubes.

For multiwall nanotubes, the following symmetry can be found [1109]. If at least one of the single-wall constituents is chiral, there are two possibilities in the commensurate case: $T_q^r C_N$, corresponding to the general mutual position, and $T_q^r D_N$ in the special mutual positions with the common U -axis. Similarly, the tube built of incommensurate components has a symmetry described by the point groups C_N or D_N . If the nanotube is built of either single-wall $(n, 0), (n', 0) \dots$ tubes or single-wall $(n, n), (n', n') \dots$ tubes, the order of the principal rotational axis is $N = G(n, n' \dots)$. If the tube contains single-wall tubes of both types, no translational periodicity appears, and its symmetry is described by a point group. On the other hand, for a tube composed of components of the same type, the translational period is equal to that of the components. Two different situations can occur: if all the integers $n/N, n'/N, \dots$ are odd ("odd" case), the translations are refined by the screw axis T_{2N}^1 ; otherwise, if at least one of these integers is even ("even" case), no screw axis emerges. Note that owing to the various arrangements of the components, any of the line and axial point groups can be the resulting symmetry for the commensurate and incommensurate components, respectively. The analysis of the special arrangements of constituents with common horizontal axes, mirror or glide planes, that increase the symmetry of the total system is summarized in Table 13.6. For periodic tubes, the line groups (and families) and the isogonal groups are in the "odd" columns if all the ratios $n/N, n'/N, \dots$ are odd, and in the "even" columns otherwise. The point groups of the tubes with both zigzag $((n0)$ chiralities) and armchair $((nn)$ chiralities) components are in the last column. In the first column, the relative positions of the component tubes are characterized by coinciding symmetry elements (beside the common principal axis in the general position). Here (U, U') denotes the horizontal axis, which is the U -axis in some of the constituents,

Table 13.6 Symmetry of the multiwall ($n0$) (zigzag) and (nn) (armchair) tubes

Relative position	Line group		Isogonal group		Point group
	“Odd”	“Even”	“Odd”	“Even”	
General	$T_{2n}^1 C_N$	(1) TC_N	C_{2N}	C_N	C_N
σ_h	$T_{2n}^1 C_{Nh}$	(4) TC_{Nh}	C_{2Nh}	C_{Nh}	C_{Nh}
σ_v	$T_{2n}^1 C_{Nv}$	(8) TC_{Nv}	C_{2Nv}	C_{Nv}	C_{Nv}
σ'_v	$T_{2n}^1 C_{Nv}$	(8) $T_c C_{Nv}$	C_{2Nv}	C_{Nv}	C_N
(U, U')	$T_{2n}^1 D_N$	(5) TD_N	D_{2N}	D_N	D_N
σ_h, σ_v	$T_{2n}^1 D_{Nh}$	(13) TD_{Nh}	D_{2Nh}	D_{Nh}	D_{Nh}
σ_h, σ'_v	$T_{2n}^1 D_{Nh}$	(13) $T_c C_{Nh}$	D_{2Nh}	D_{Nh}	C_{Nh}
(σ_h, σ'_h)	$T_{2n}^1 C_{Nh}$	(4) TS_{2N}	C_{2Nh}	S_{2N}	S_{2N}
$(\sigma_h, \sigma'_h), \sigma_v$	$T_{2n}^1 D_{Nh}$	(13) TD_{Nd}	D_{2Nh}	D_{Nd}	D_{Nd}
$(\sigma_h, \sigma'_h), \sigma'_v$	$T_{2n}^1 D_{Nh}$	(13) $T_c S_{2N}$	D_{2Nh}	D_{Nd}	S_{2N}

and the U' -axis in the remaining ones (thus, additional mirror or glide planes are excluded). Also, (σ_h, σ'_h) is a plane which is σ_h in some of the constituents (with n necessarily even) and σ'_h in the remaining tubes; in the incommensurate case, the same groups are obtained when they have common σ'_h planes.

13.2.6 Use of Symmetry in Nanotube LCAO Calculations

The lack of the crystallographic restrictions for line groups makes translations just a small part of the full symmetry, in contrast to space and layer groups. While in the unit cell of a three-dimensional crystal there are typically several to hundred atoms, the unit cell of a typical nanotube includes hundreds or thousands of atoms. The majority of the existing ab initio numerical codes do not implement line group symmetry. One of the first attempts of such an implementation was made in [1112] to calculate the graphene nanotubes by the method of linear augmented cylindrical waves. Using the symmetry-adapted version of this method, carbon nanotubes containing up to 118 804 atoms per translational unit cell (the chiral vector $\mathbf{R}(100, 99)$, helical axis order 59402) were calculated. Even for the largest system with a huge unit cell, the band structure can be easily calculated, and the results can be presented in the standard form of four curves for the valence band plus one curve for the low-energy states of the conduction band.

Recently the rototranslational (helical) symmetry was implemented in CRYSTAL09 code [953, 1111] and used in the first-principles LCAO calculations of carbon nanotubes. To the best of our knowledge, this is the first complete, tested, and documented implementation of helical point symmetry in a general-purpose computer code. It has been shown that the use of the helical symmetry of nanotubes, usually quite high, permits one to drastically reduce the computational time and tackle large unit-cell nanotubes with an extended basis set. The code permits one to

pass from a 3D object (bulk crystal) to a 2D slab and then to a 1D nanotube in a fully automatic way.

In the direct space, the helical symmetry is exploited for the calculation of mono- and bielectronic integrals, so that only a small fraction (the irreducible wedge) of the Fock (Kohn–Sham) matrix F is explicitly computed. The saving factor in the computing time can be as large as N , where N is the number of point symmetry operators that characterize the system.

The symmetry in the reciprocal space is also exploited, as the matrices corresponding to each irreducible representation (IR) are individually diagonalized for the considered $\mathbf{k}$ points. By transforming the Bloch basis into a symmetry-adapted basis, the Fock matrix $F\mathbf{k}$ becomes block diagonal, with each block corresponding to an irreducible representation (IR) of the point group. When the system is periodic only along one direction (z in our convention) and the rotation part of the symmetry operators acts on the Cartesian coordinates (x and y) orthogonal to the translation direction, the point group of each $\mathbf{k}$ point is the same, and contains the full set of point operators. The Fock matrix then factorizes in exactly the same way at each $\mathbf{k}$ point. As the cyclic group Z is Abelian, the number of IRs (and of blocks to be diagonalized) is equal to the number of rototranslation operators. In this case, the saving factor is much larger than N , due to the third-to-fourth order scaling of the diagonalization process. As a matter of fact, the dimension of all the diagonalized matrices is $M = mN_{AO}$, where N_{AO} is the number of atomic orbitals describing each atom and m is the number of atoms in the layer unit cell.

Following [111], we consider the use of helical symmetry in the first-principles calculations of carbon nanotubes. The structure of a carbon nanotube is modeled by rolling up a single sheet of graphite (i.e., graphene) into a cylinder along the given translation vector $\mathbf{R}(n_1, n_2)$ in a plane hexagonal lattice with two carbon atoms in the primitive cell. The symmetry of graphene is given by layer group $80(P6/mmm)$. It is seen from Table 13.5 that this layer group generates nanotubes with the symmetry of the line group $L^{(5)}$ (the fifth family) when the general chiral vector $\mathbf{R}(n_1, n_2)$ is used for rolling up the tube (chiral carbon nanotubes). Zigzag and armchair achiral nanotubes are obtained by rolling up the special chiral vectors $\mathbf{R}(n, 0)$ and $\mathbf{R}(n, n)$, respectively. The symmetry of these tubes is given by the line group $L^{(13)}$; see Table 13.5. The isogonal point groups of the carbon chiral and achiral nanotubes are D_n and D_{2nh} , with the helical symmetry axis orders equal to n and $2n$, respectively. The resulting nanotubes contain $2q$ and $4q$ atoms, respectively, that is, dozens or hundreds of atoms in the unit cell, depending on the chiral vector choice. As an example, consider the (24,0) nanotube; with the basis set used for calculations in [111] (a 6-1111 G^* contraction), the size of the Fock matrix in the AO basis is 2112 (22 AOs times 96 atoms); in the symmetry-adapted basis, there are 48 blocks, each containing 44 lines. Then 48 44×44 matrices are diagonalized at each $\mathbf{k}$ point.

It is clear that the reduction in computational time due to this factorization is dramatic, in particular, in the case of highly symmetric systems with large unit cells, for which the diagonalization requires a large fraction of the overall computing time. Table 13.7 demonstrates the effect of using of the helical point symmetry in the

Table 13.7 Effect of the exploitation of point symmetry in the simulation of carbon nanotubes of increasing size [1111]

	R	N_A	N_{AO}	N_R	$N_{\hat{S}}$	t_{SCF}	t_G	ΔE	δE
(8,0)	3.137	32	704	15.8	16	72.1	459.6	42.78	1.48
(9,0)	3.529	36	792	17.8	18	65.9	409.2	34.47	0.728
(10,0)	3.921	40	880	19.8	20	63.0	384.3	27.20	0.475
(11,0)	4.313	44	968	21.8	22	60.7	365.0	22.57	0.387
(12,0)	4.705	48	1,056	23.8	24	60.6	355.2	19.50	0.126
(13,0)	5.097	52	1,144	25.8	26	61.4	353.9	16.24	0.117
(14,0)	5.489	56	1,232	27.8	28	62.8	350.1	14.08	0.134
(15,0)	5.881	60	1,320	29.7	30	63.4	352.6	12.65	0.0518
(16,0)	6.273	64	1,408	31.7	32	65.2	346.9	10.88	0.0685
(17,0)	6.665	68	1,496	33.7	34	66.5	344.3	9.70	0.0750
(18,0)	7.058	72	1,584	35.7	36	67.9	341.0	8.93	0.0195
(19,0)	7.450	76	1,672	37.7	38	70.2	344.1	7.86	0.0320
(20,0)	7.842	80	1,760	39.6	40	72.5	344.6	7.14	0.0386
(21,0)	8.234	84	1,848	41.6	42	75.4	344.9	6.68	0.0151
(22,0)	8.626	88	1,936	43.6	44	78.4	347.1	5.97	0.0162
(23,0)	9.018	92	2,024	45.6	46	81.7	348.6	5.49	0.0243
(24,0)	9.410	96	2,112	47.6	48	85.6	351.5	5.20	8.63E-3

simulation of carbon nanotubes of increasing size. The results are taken from [1111]. The geometry of a set of carbon zigzag $(n, 0)$ nanotubes was optimized. Structure optimizations were performed by using analytical energy gradients with respect to atomic coordinates and unit-cell parameters. Convergence was checked on both gradient components and nuclear displacements. The hybrid B3LYP functional was adopted, together with a quite complete basis set containing $1s$, $4sp$, and $1d$ shells, that is 22 AOs per carbon atom (6-1111G* contraction). The level of accuracy in evaluating the Coulomb and Hartree–Fock exchange series is controlled by five parameters, [953] for which the 8 8 8 8 16 values were used. The threshold on the SCF energy was set to 10^{-8} Ha. The reciprocal space was sampled according to a regular sublattice with shrinking factor 10 (6 $\mathbf{k}$ vectors). The DFT exchange–correlation contribution was evaluated by numerical integration over the unit-cell volume. In these calculations, a (75,974) grid was used which corresponds to a pruned grid with 75 radial and 974 angular points; the accuracy in the integration can be estimated by the error in the integrated electronic charge density in the unit cell ($\Delta_e = 810^{-4}|e|$ for a total of 576 electrons in the (24,0) nanotube).

Table 13.7 documents the effect of point symmetry use for a set of $(n, 0)$ nanotubes (all of them share the same rolling direction). In the first two columns, the (n_1, n_2) indices of the nanotubes and their radius, R (Å), are reported. N_A and N_{AO} are the number of atoms and atomic orbitals in (6-1111G(d)) basis set per unit cell, N_R is the ratio between the number of elements of the complete and irreducible Fock matrix, and $N_{\hat{S}}$ is the number of symmetry operators. The cost of the calculation is documented in the t_{SCF} and t_G columns of Table 13.7; t_{SCF} and t_G are given in seconds and mean the time of a single SCF cycle and of the gradient calculation, respectively (single processor-Intel Xeon, 1.86 GHz, RAM 8 Gb). ΔE and δE

(kJmol⁻¹ per couple of C atoms) are the energy difference with respect to graphene and the relaxation energy after rigid rolling, respectively.

In going from (8,0) to (24,0), the number of atoms (N_A), basis functions (N_{AO}), and symmetry operators ($N_{\hat{S}}$) increase exactly by threefold (from 32 to 96, from 704 to 2112, and from 16 to 48, respectively). The complete Fock matrix for the largest case is then about three times larger than for the (8,0) case, whereas the symmetry-adapted matrix size is roughly constant. The (8,0) nanotube F matrix has about 11,500 elements that diminish to 10,000 for the (24,0) case. The number of elements N_R is extremely close to the number of symmetry operators $N_{\hat{S}}$. The time required for the calculation of bielectronic integrals, the most expensive part of the SCF calculation, decreases for a while and then remains nearly constant. The same behavior is shown by the gradient, whose cost from (12,0) to (24,0) varies by less than 1%. The overall cost of the SCF cycle increases (slowly) for three reasons. First, the diagonalization step scales linearly with N (i.e., with the number of symmetry operators and with the number of atoms). Second, the t_{SCF} and t_G $AO \rightarrow Bloch \rightarrow symmetry$ -adapted basis transformations, and the back transformations to the AO basis for building the density matrix, are matrix multiplications. In principle, $AO \rightarrow Bloch$ and $Bloch \rightarrow symmetry$ -adapted basis transformations should scale as N_{AO}^2 and N_{AO}^3 , respectively, with a low prefactor. In practice, the sparsity of all the involved matrices is exploited so that the scaling of this stage is closer to N_{AO}^2 than to N_{AO}^3 . Third, the overhead for the symmetry analysis increases with the number of symmetry operators. Overall, the total cost increases by less than 50% for the SCF and remains constant for the gradient, whereas in a perfect linear scaling code, not exploiting the symmetry, the cost would increase by a factor of three. The last two columns provide the energy difference between the relaxed nanotube and graphene, $\Delta E = E_{relaxed} - E_{graphene}$, and the relaxation energy after rigid rolling, δE (energy difference between unrelaxed and relaxed nanotubes). Roughly speaking, both ΔE and δE decrease regularly as n increases, as expected and in line with the previous findings. Actually, a finer analysis shows that δE data belongs to three different curves, describing the $(3n, 0)$, $(3n + 1, 0)$, and $(3n + 2, 0)$ cases; however, the differences are quite small and tend to disappear with the increase of the nanotube diameter. The stability of a nanotube family with respect to graphene calculated at the B3LYP level documents the feasibility of this kind of calculations, and the accuracy of the implementation [1111].

13.3 LCAO Calculations on BN and TiO₂ Nanotubes with Hexagonal Morphology

13.3.1 Single-Wall BN and TiO₂ Nanotubes

Boron nitride and titania are well-known semiconductors comprehensively studied in materials science, thanks to their widespread technological applications. Six polymorphs of BN have been established so far (including amorphous structure), the most stable among them are cubic and hexagonal phases.

The number of discovered TiO₂ polymorphs is seven [581], with rutile and anatase undoubtedly prevailing because of their higher stability as compared to other titania phases [1126]. These polymorphs exhibit different properties. Anatase transforms irreversibly to rutile at elevated temperatures. The temperature of this transformation is not unique, and the processes involved in the transformation were comprehensively reviewed in [1126].

Nanotubes (NTs) of different morphology were systematically synthesized in the last 10–15 years and carefully studied as promising technological materials, both for BN [1127, 1128] and TiO₂ [1129, 1130]. One of the recently discovered nanotube applications was the doping of TiO₂ NTs by boron and nitrogen atoms [1131] gradually varying their bandgaps.

Since the growth mechanism for both BN and TiO₂ nanotubes is not well yet defined, their comprehensive theoretical studies attract enhanced attention. Numerous simulations have been already performed on the 1D single-wall (SW) and multiwall (MW) models of BN nanotubes possessing hexagonal honeycomb morphology and the two equilibrium structures with either armchair (n, n) or zigzag ($n, 0$) type chirality and a wide range of uniform diameters (0.5–2 nm) [1123, 1132–1135]. In most theoretical simulations on titania nanotubes, the model $3D \rightarrow 2D \rightarrow 1D$ of structural transformations described in [1136] was applied, that is, the bulk (3D) phase first formed a lamellar product ($3D \rightarrow 2D$) and then was bent and rolled to a nanotubular form ($2D \rightarrow 1D$). The lamellar product was mainly formed by anatase the (101) surface, identified as prevailing in TiO₂ NTs [1116, 1137, 1140–1142]. A further geometry optimization of the 3-layer O–Ti–O sheet for $2D \rightarrow 1D$ transition results in the formation of titania nanotubes possessing hexagonal fluorite-like (111) morphology with (n, n) and ($n, 0$) chiralities [1122]. In reality this hexagonal structure can only exist in the metastable phase of bulk titania under extremely high pressure [581].

In the case of BN the folding procedure is applied to a graphene-like (0001) nanosheet cut from the most stable phase of the bulk crystal with the hexagonal space group $194 P6_3/mmc$. The sheet symmetry is described by the layer group $78 P\bar{6}m2$; see Table 13.8. For comparison, the layer group of graphene (0001) nanosheet is also given. In both cases, all the rolled sheet atoms are distributed over the NT cylindrical surface.

Theoretical simulations on TiO₂ nanosheets originating from the three-layer O–Ti–O model were widespread as simpler systems for simulations [1141]. When the structures of a 3-layer (101) slab cut from anatase bulk were being optimized, only the structure of the (111) fluorite-type slab was recently obtained [1122], which exhibits sixfold coordinated titanium atoms and twofold coordinated oxygens. The three-layer nanosheets cut from the fluorite phase of the bulk TiO₂ (the space group $225 Fm\bar{3}m$) have the symmetry of the layer group $72 P\bar{3}m1$; see Table 13.8.

Using the rolling up correspondence of the line and layer groups (see Table 13.5), one obtains line groups for special chiralities of graphene, BN, and TiO₂ nanotubes (see Table 13.8). The corresponding isogonal point groups P_l and line groups for general chiralities (n_1, n_2) are also given in Table 13.8.

Table 13.8 Line symmetry groups of SW BN and TiO₂ nanotubes rolled up from hexagonal nanosheets. For comparison, the layer group of graphene is added

Object	Space group for C, BN, and TiO ₂ bulk	Layer	Layer group	Line groups for special chiralities*	P_I	Line groups for general chiralities (n_1, n_2)
Graphene, monolayer	194 $P6_3/mmc$	(0001)	80($P6/mmm$)	13i $(2n)_n/mcm$	D_{2nh}	5 $n_q 22(D_q)$
BN, monolayer	194 $P6_3/mmc$	(0001)	78($P\bar{6}m2$)	$4h(2n)_n/m$ $8g(2n)_nmc$	C_{2nh} C_{2nv}	1 $n_q(C_q)$
3-layer TiO ₂ slab (fluorite)	225 $Fm\bar{3}m$	(111)	72($P\bar{3}m1$)	$4h(2n)_n/m$ $8g(2n)_nmc$	C_{2nh} C_{2nv}	1 $n_q(C_q)$

* Special chiralities: $g(n, 0)$, $(0, n)$, $(-n, n)$; $h(n, n)$, $(-n, 2n)$, $(-2n, n)$; $i(n, 0)$, $(0, n)$, $(-n, n)$, (n, n) , $(-n, 2n)$, $(-2n, n)$

The first-principles LCAO calculations on hexagonal BN and titania nanosheets as well as nanotubes have been performed in [1123] using the hybrid Hartree–Fock/Kohn–Sham exchange–correlation functional (PBE0).

When modeling the hexagonal BN bulk, the all-valence basis sets (BSs) for B and N atoms in the form of 6s-21sp-1d and 6s-31p-1d Gaussian-type functions (GTFs), respectively, were used in [1123]. Further BS optimization gave rather negligible changes of the virtual orbitals of BN. The calculated equilibrium lattice constants for the bulk of hexagonal BN structures have been found to be qualitatively close to their experimental values, given in brackets: a_0 of 2.51 Å (2.50 Å) and b_0 of 7.0 Å (6.7 Å), thus indicating a reliable optimization of BN BSs, [1135]. On the other hand, unlike the optical bandgap measured experimentally (5.96 eV for BNhex bulk [1143]), the calculated value of the gap is found to be noticeably larger (6.94 eV at K point of BZ), which is largely a result of applying the PBE0 hybrid functional to BN calculations (the PWGGA functional gave a better agreement of these values [1135]).

The small-core pseudopotential [884] of the Ti atom was used in titania nanotube calculations (3s-, 3p-, 3d-, and 4s-electrons were taken as valence electrons), while the all-electron BS for the O atom was taken from [1144]. It is well known that in the LCAO calculations of crystals, the BS of a free atom has to be modified as the diffuse functions cause numerical problems because of the large overlap with the core functions of the neighboring atoms in a densely packed crystal [1145]. To optimize the BS, the minimization method without calculations of the total energy derivatives (the method of conjugate directions, developed by Powell [1146]) was used in [1123]. The diffuse exponents of valence s, p, and d orbitals have been optimized for stable anatase phase of bulk titania. Its atomic and electronic properties have been reproduced in the good agreement with the experiment (the experimental values are given in brackets): the lattice parameters $a = 3.784$ Å (3.782 Å) and $c = 9.508$ Å (9.502 Å), the dimensionless parameter for the relative position of the oxygen atom $u = 0.2074$ (0.2080), although the values

Table 13.9 The structural and electronic properties of the optimized BN hexagonal bulk and (0001) nanosheet

	Lattice parameters		Bond length d_{B-N}	Effective charge q_B^a	E_{surf}	$\Delta\epsilon_{\text{gap}}$
Models of BN	a	c				
Bulk and Sheet	(Å)	(Å)	(Å)	(e)	(J/m ²)	(eV)
bulk	2.50	6.90	1.445	1.01	–	6.94
sheet	2.50	–	1.444	0.99	0.04	7.09

^aAveraged effective charges q_N are the same as q_B , with opposite sign

of the gap are less accurate still, again because of being overestimated: 4.0 eV versus 3.2 eV. In any way, these results for the bulk titania (anatase) agree with the experimental data better than those given in [1147] for both the plane wave (PW) and LCAO calculations when using the different exchange–correlation potentials. Certain improvement on the substantially underestimated values of the gap for the bulk anatase in the DFT PW calculations has been achieved recently [1142] using the LDA + U method (2.7 eV).

Monoperiodic translation symmetry has been adopted for nanotube calculations as it was implemented in CRYSTAL09 code [953], containing also a special input option which allows the generation of 1D nanotubes from 2D slabs.

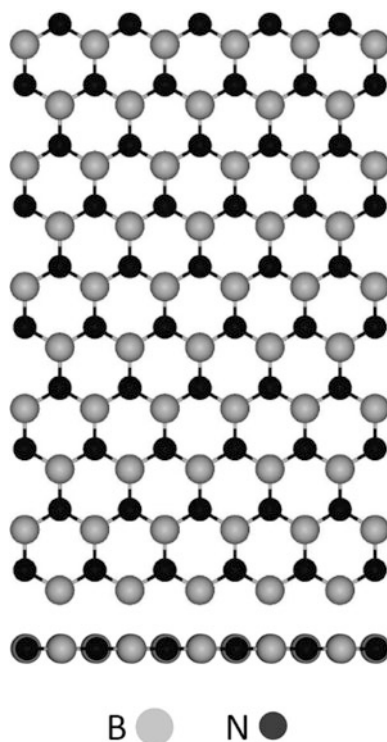
The description of the hexagonal BN bulk and the (0001) monolayer, which is similar to the hexagonal structure of the graphite bulk and the graphene nanosheet, respectively, precedes the description of properties for the BN nanotubes, in accordance with the model of structural transformation $3D \rightarrow 2D \rightarrow 1D$, [1134] which means (a) cutting a monolayer and (b) then rolling it to an SW NT. The surface energy E_{surf} (see Table 13.9 and Fig. 13.3) is calculated as $(E_n - nE_b)/(2S)$, where E_n is the total energy of the n -layer slab per primitive surface unit cell and S —its area, while E_b is the total energy per primitive bulk unit cell.

The B–N bond population in a semi-covalent boron nitride has been found to be 0.575 e for the bulk and 0.600 e for the nanosheet (the former has to be smaller due to a partial interbonding of neighboring (0001) layers in the hexagonal BN bulk). The maximum of the electron density within the B–N bond is localized closer to the midpoint along the semi-covalent bond, which can be explained by a proximity of the ionic radii of the B and N atoms as a result of the electronic charge transfer.

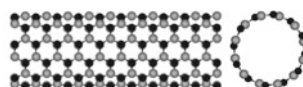
BN nanosheets (see Fig. 13.3) are rolled up to BN nanotubes of different chiralities.

For BN NTs of (n, n) and $(n, 0)$ chiralities (Fig. 13.4) and gradually growing nanotubes diameters D_{NT} (D_{NT} varies from 0.5 up to 3.3 nm), the number of different properties is analyzed in Table 13.10. The relaxation energy E_{relax} is defined as the difference (per BN formula unit) between the energies of NTs before and after the geometry optimization. The nonrelaxed NTs are rolled up from the optimized nanosheets. The strain energy E_{strain} is defined as the difference (per BN formula unit) between the E_{NT} (the total energy per unit cell of the relaxed NT) and kE_{slab} , where k is the number of slab unit cells.

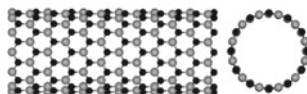
Fig. 13.3 BN (0001)
nanosheet: top and across
views



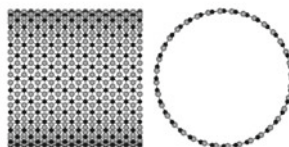
(a) optimized single-wall (6,6) *ac*-BN NT
(aside and across images), $D_{NT} = 0.84$ nm;



(b) optimized single-wall (12,0) *zz*-BN NT
(aside and across images), $D_{NT} = 0.96$ nm;



(c) optimized single-wall (18,18) *ac*-BN NT
(aside and across images), $D_{NT} = 2.49$ nm;



(d) optimized single-wall (36,0) *zz*-BN NT
(aside and across images), $D_{NT} = 2.87$ nm.



Fig. 13.4 Lateral (aside) and cross-sectional (across) images of hexagonal single-wall BN nanotubes with different chiralities and diameters

Table 13.10 The structural and electronic properties of optimized BN nanotubes

NT chirality indices	N_a^a	l_{NT}^b , Å	D_{NT} , Å	d_{BN} , Å	q_B , e	E_{relax} , eV/BN	E_{strain} , kJ/mol per BN	$\Delta\varepsilon_{gap}$, eV
<i>(n, n)</i> nanotubes - C_{2nh} (family 4)								
(4,4)	16	2.505	5.49	1.449	0.990	−0.086	34.69	6.69
(6,6)	24	2.503	8.39	1.447	1.010	−0.035	16.22	6.98
(12,12)	48	2.502	16.61	1.446	1.003	−0.010	5.56	7.01
(18,18)	72	2.502	24.87	1.445	0.997	−0.005	2.14	6.99
(24,24)	96	2.502	33.13	1.445	0.995	−0.004	1.24	7.00
<i>(n, 0)</i> nanotubes - C_{2nv} (family 8)								
(6,0)	24	4.303	5.01	1.442	0.986	−0.110	46.78	4.96
(12,0)	48	4.328	9.56	1.444	1.012	−0.022	12.44	6.58
(18,0)	72	4.331	14.41	1.444	1.008	−0.010	5.92	7.00
(24,0)	96	4.332	19.12	1.444	1.001	−0.006	2.48	6.98
(36,0)	144	4.333	28.67	1.444	0.994	−0.003	1.62	6.96

^a N_a —number of atoms *per* nanotube unit cell
^b l_{NT} —length of NT unit cell along translation vector

For a small D_{NT} (low chirality indices), the absolute values of both the relaxation and the strain energies are large enough. The attempt to reduce these diameters even more gives greater instability of NTs. Since the results for the hypothetical nanotubes with an infinite diameter should coincide with those for the (0001) monolayer, a consequent growth of the NT diameters leads to a substantial decrease of both relaxation and strain energies (down to zero at infinity). It is seen from Table 13.10 that the values of l_{NT} (the length of NT unit cell along the translation direction), the bond $B - N$ length d_{B-N} , the atomic charge q_B , and the energy gap $\Delta\varepsilon_{gap}$ approach those for the BN sheet (Table 13.9).

TiO₂ sheets with a thickness of a few atomic layers were found to be remarkably stable [1148]. Theoretical simulations on TiO₂ nanosheets and nanotubes obtained from 3-layer O–Ti–O slabs (Fig. 13.5) were quite widespread as more simple systems for simulations [1141].

The main results obtained by means of the LCAO PBE0 calculations [1123] for this slab are compared with the corresponding bulk properties of the titania anatase phase in Table 13.11. The relaxation energy for the 3-layer TiO₂ slab cut from the anatase bulk and transformed into (111) fluorite-type morphology is really large, while its surface and formation energies are qualitatively similar to those calculated earlier [1142, 1148]. Since the optimized 3-layer slab has a hexagonal structure, its parameters cannot be compared directly with those for the titania anatase bulk.

Three-layer titania nanosheets with a hexagonal fluorite-like (111) structure can be rolled up to 3-layer titania SW NTs with (a) armchair-type (n, n) chirality and (b) zigzag-type $(n, 0)$ chirality. The structural and electronic properties of several hexagonal three-layer titania nanotubes are given in Table 13.12. The optimized structures of four selected nanotubes of both chiralities (two nanotube models per each chirality) are shown in Fig. 13.6.

Fig. 13.5 Sixfold coordination of Ti atoms in a stoichiometric three-layer hexagonal nanosheet (a) and its top and cross-sectional images (b)

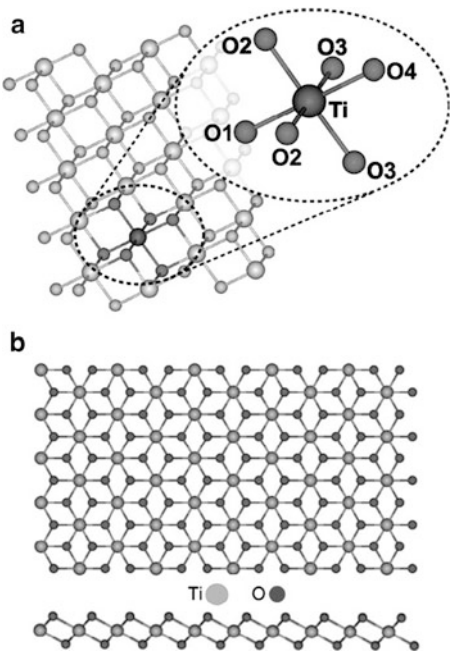


Table 13.11 The atomic and electronic structure of the optimized TiO₂ anatase bulk versus the fluorite-like (111) titania slab

Lattice			Bond length $d_{\text{Ti-O}}^{\text{a}}$						E_{relax}		
Models of parameters			Thickness ($\text{\AA}$)				Effective charge		per TiO ₂		
TiO ₂ bulk	$\text{\AA}$										
and sheets	a	c	h_{NT} ($\text{\AA}$)	Ti – O1	Ti – O2	Ti – O3	Ti – O4	q_{Ti}^{b} (e)	unit, eV	E_{surf} J/m ²	$\Delta\epsilon_{\text{gap}}$ eV
Bulk	3.78	9.51	–	1.935	1.935	1.973	1.973	2.35	–	–	4.09
3-layer (fluorite-like)	2.96	–	1.92	1.95	1.96	1.97	1.98	2.45	–6.05	0.44	4.89

^aThe corresponding bonds are shown in Fig. 13.5
^bAveraged effective charges q_{O} are twice smaller than q_{Ti} , with the opposite sign

As to Ti–O bond lengths, their deformation is more noticeable for smaller values of $d_{\text{Ti-O}}$, gradually approaching those in a three-plane nanosheet; see Table 13.11. Obviously, this is also true for the convergence of E_{relax} with D_{NT} increasing (Table 13.12). The strain energies and bandgap dependence on D_{NT} for all the four sets of three-layer TiO₂ NTs are shown in Figs. 13.7 and 13.8, respectively.

The range of nanotube diameters considered is sufficiently large, from 0.5 to 4.0 nm, with the number of atoms per NT unit cell increased from 30 to 288. The calculations with the total geometry optimization for a total of 20 one-periodic models of TiO₂ NTs of different morphologies were performed in [1123].

The two curves $E_{\text{strain}}(D_{\text{NT}})$ shown in Fig. 13.7 for two chiralities of titania nanotubes confirm the conclusions drawn above from Table 13.12. When the diameters of nanotubes increase up to 40 $\text{\AA}$ all the strain energies substantially

Table 13.12 The structural and electronic properties of hexagonal 3-layer TiO₂ NTs^a

Chirality of nanotube	N_A	$l_{NT}, D_{NT}, h_{NT},$				$d_{Ti-O}, \text{\AA}$				$q_{Ti},$ e	$E_{relax},$ per TiO ₂ , eV	$E_{strain},$ per TiO ₂ , kJ/mol	$\Delta\varepsilon_{gap},$ eV
		$\text{\AA}$	$\text{\AA}$	$\text{\AA}$		Ti – O1	Ti – O2	Ti – O3	Ti – O4				
		$(2n)_n/m$ group - $C_{2n,h}$ (family 4)											
(6,6)	36	2.991	10.06	1.86	1.89	1.94	2.00	2.05	2.42	−0.09	46.18	4.66	
(9,9)	54	2.98	14.88	1.89	1.91	1.94	1.99	2.02	2.43	−0.05	20.11	4.74	
(12,12)	72	2.97	19.73	1.91	1.935	1.95	1.98	1.995	2.44	−0.04	11.26	4.77	
(15,15)	90	2.97	24.61	1.91	1.94	1.95	1.98	1.99	2.45	−0.04	7.20	4.79	
(18,18)	108	2.97	29.51	1.91	1.945	1.955	1.97	1.98	2.45	−0.03	5.04	4.80	
$(2n)_{nmc}$ group - $C_{2n,v}$ (family 8)													
(8,0)	48	5.065	8.17	1.83	1.89	1.94	1.955	2.135	2.40	−0.33	76.43	4.65	
(12,0)	72	5.10	11.70	1.88	1.915	1.945	1.96	2.03	2.43	−0.09	33.71	4.70	
(18,0)	108	5.12	17.23	1.90	1.935	1.95	1.965	1.965	2.44	−0.05	14.93	4.75	
(24,0)	144	5.12	22.88	1.91	1.94	1.95	1.97	1.985	2.45	−0.04	8.55	4.79	
(30,0)	180	5.125	28.55	1.92	1.945	1.955	1.975	1.98	2.45	−0.04	5.52	4.82	

^aDefinitions of values are the same as in Tables 13.10–13.11

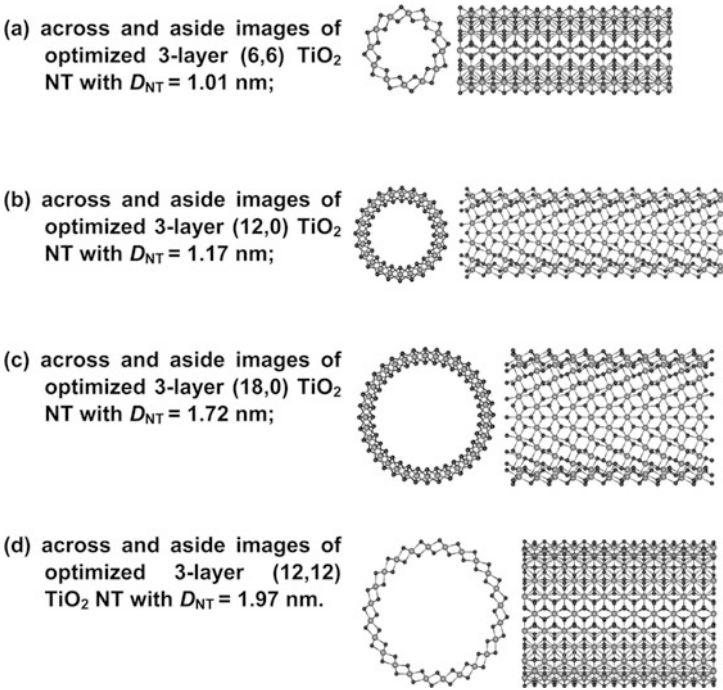


Fig. 13.6 Cross-sectional (across) and lateral (aside) images of hexagonal single-wall TiO₂ nanotubes with different chiralities and diameters

Fig. 13.7 Strain energies E_{strain} versus D_{NT} for the two sets of single-wall TiO₂ nanotubes with various chiralities

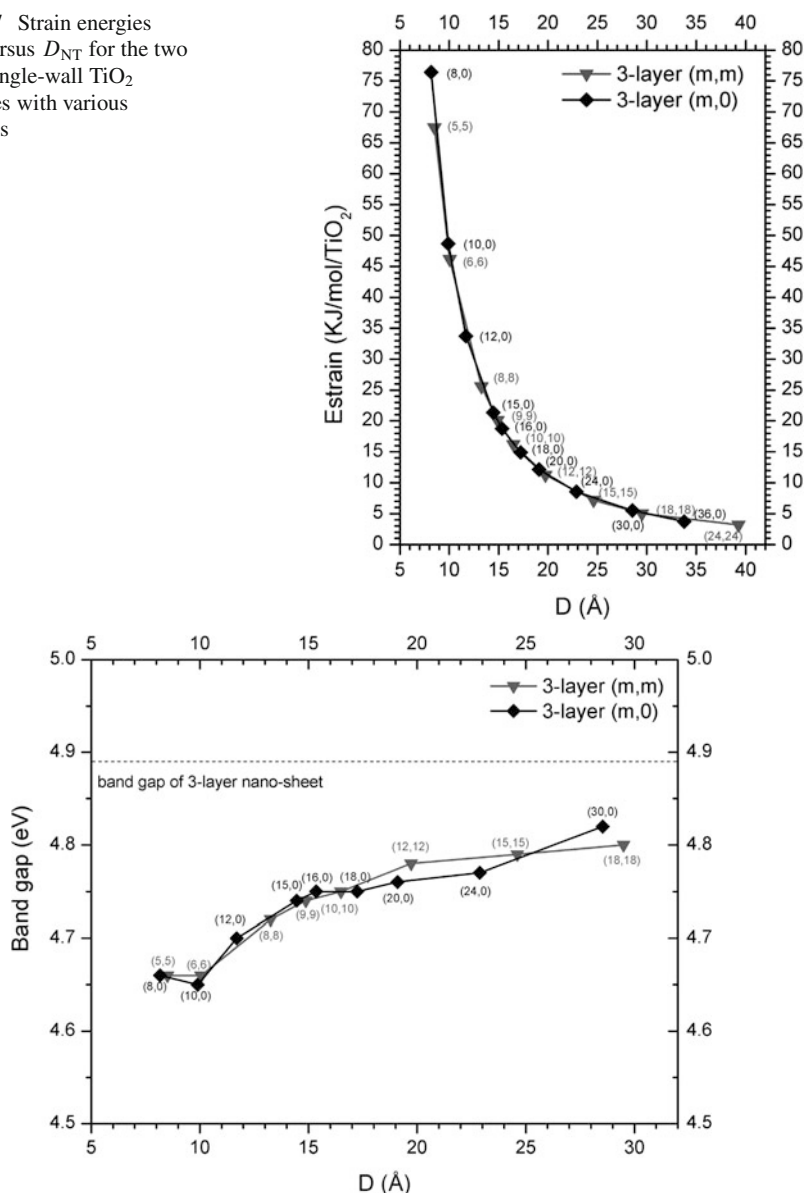


Fig. 13.8 Bandgaps $\Delta\epsilon_{\text{gap}}$ versus D_{NT} for the two sets of single-wall TiO₂ nanotubes with various chiralities

decrease and approach each other. One expects that further increase of D_{NT} can result in slightly smaller values of E_{strain} for 3-layer nanotubes. In the three-layer nanotubes of similar diameters, the difference of the strain energies for fluorite-type (n, n) and $(n, 0)$ chiralities is fairly negligible, which supports qualitatively similar

results obtained earlier for these types of nanotubes [1137, 1141, 1142]. Figure 13.8 presents $\Delta\epsilon_{\text{gap}}$ dependence on D_{NT} . When nanotube diameters markedly increase, their bandgaps $\Delta\epsilon_{\text{gap}}$ asymptotically approach those for the corresponding 2D slabs (Table 13.11), in a similar way to hexagonal BN NTs (Table 13.10). However, the nanotube diameters considered are too small for a direct comparison with the slabs.

13.3.2 Double-Wall BN and TiO₂ Nanotubes

Large-scale first-principles simulations on BN double-wall (DW) NTs were performed, either for $(n_1, 0)@(n_2, 0)$ chirality [1149, 1150] alone or for both $(n_1, 0)@(n_2, 0)$ and $(n_1, n_1)@(n_2, n_2)$ chiralities [1151]. In these studies, the bandgaps of DW NTs were found to be smaller than those of the corresponding SW NTs. Owing to the large curvature of the BN nanotubes, which induces hybridization between the σ and π states of both nanotubes, the top of valence and the bottom of conduction bands were found to be localized on the outer and inner nanotubes, respectively [1149]. Both zigzag, zz -(8, 0)@(16, 0), and armchair, ac -(5, 5)@(10, 10), DW NTs were found to be the most stable energetically among double-wall BN nanotubes with different chiralities, although the interwall stacking gives an energetic preference for the growth of zigzag nanotubes. Meanwhile, the theoretically described second-order nonlinear optical coefficients of DW BN NTs were found to be significantly reduced by the interwall interaction, as compared to SW BN NTs [1152]. Thus, it is very important to investigate the multiwall structures for the purpose of revealing the underlying physical phenomena, even though the interwall interaction might be weak [1155].

The line symmetry group $L_2 = Z_2P_2$ of a double-wall (DW) nanotube can be treated as an intersection of the symmetry groups L_0 and L_1 of its single-wall constituents; see Sect. 13.2.5 and references [1109, 1121]. The coaxial hexagonal DW NTs $(n_1, n_1)@(n_2, n_2)$ and $(n_1, 0)@(n_2, 0)$ are commensurate; the translation period of such DW NTs is the same as for their constituents.

Table 13.13 gives the symmetry of commensurate DW BN and TiO₂ NTs with hexagonal morphology, including both multiple DW nanotubes (armchair $(n, n)@M(n, n)$ and zigzag $(n, 0)@M(n, 0)$, part a), and nonmultiple DW nanotubes containing arbitrary SW constituents (armchair $(n_1, n_1)@(n_2, n_2)$ and zigzag $(n_1, 0)@N(n_2, 0)$, part b).

LCAO PBE0 calculations of DW BN and TiO₂ nanotubes with hexagonal morphology are made in [1124] and allow one to compare their properties with those for the corresponding single-wall nanotubes. The calculations were performed using the CRYSTAL09 computer code [953] and HELIX option which takes into account only rototranslational symmetry (the order of rototranslational axis has to be not larger than 48). As seen from Table 13.13, the DW NTs under consideration have twice times more symmetry operations than the order of the rotohelical axis (reflections in vertical or horizontal planes are added to the rotohelical rotations). Using the TESTGEOM-NANOTUBE option as foreseen in the CRYSTAL09 code,

Table 13.13 Symmetry of DW BN and TiO₂ NTs with hexagonal morphology

(a) Multiple double-wall nanotubes $(n_1, n_1)@M(n_1, n_1)$ and $(n_1, 0)@M(n_1, 0)$				
DW NT chiralities	Multiple divisor M	Line group	Point group	Substance
(4, 4)@(8, 8)	2	$4/m$	C_{4h}	BN
(4, 4)@(12, 12)	3	$8_4/m$	C_{8h}	TiO ₂
(5, 5)@(10, 10)	2	$\overline{10}$	C_{5h}	BN
(6, 6)@(12, 12)	2	$6/m$	C_{6h}	BN, TiO ₂
(6, 6)@(18, 18)	3	$12_6/m$	C_{12h}	TiO ₂
(7, 7)@(14, 14)	2	$\overline{14}$	C_{7h}	TiO ₂
(8, 8)@(16, 16)	2	$8/m$	C_{8h}	TiO ₂
(8, 8)@(24, 24)	3	$16_8/m$	C_{16h}	TiO ₂
(9, 9)@(18, 18)	2	$\overline{18}$	C_{9h}	BN
(6, 0)@(12, 0)	2	$6mm$	C_{6v}	BN
(7, 0)@(14, 0)	2	$7m$	C_{7v}	BN
(8, 0)@(16, 0)	2	$8mm$	C_{8v}	BN, TiO ₂
(8, 0)@(24, 0)	3	16_8mc	C_{16v}	TiO ₂
(9, 0)@(18, 0)	2	$9m$	C_{9v}	BN, TiO ₂
(10, 0)@(20, 0)	2	$10mm$	C_{10v}	BN, TiO ₂
(12, 0)@(24, 0)	2	$12mm$	C_{12v}	BN, TiO ₂
(12, 0)@(36, 0)	3	$24_{12}mc$	C_{24v}	TiO ₂
(b) Multiple double-wall nanotubes $(n_1, n_1)@M(n_2, n_2)$ and $(n_1, 0)@M(n_2, 0)$				
DW NT chiralities	Common divisor N	Line group	Point group	Substance
(4,4)@(9,9)	1	m	C_s	BN
(6,6)@(10,10)	2	$4_2/m$	C_{4h}	BN
(12,0)@(28,0)	4	8_4mc	C_{8v}	TiO ₂

all the atomic coordinates in the monoperiodic unit cell were generated from 2D slabs for both constituent SW NTs separately. Being added to the input, they describe the initial DW NT atomic coordinates.

The calculations of double-wall nanotubes that have large unit cells (containing up to 288 atoms in the case of (12, 0)@(36, 0) and TiO₂ NTs) were performed using the full exploitation of the helical rototranslational symmetry. The coordinates of all the atoms in the nanotube unit cells were allowed to relax when the optimization procedure was performed.

Two different commensurate DW NTs can be constructed from a given pair of SW NTs rolled up from the hexagonal sheets of BN or TiO₂. There is no second-order symmetry axis perpendicular to the BN or TiO₂ layers under consideration. This means that the rotation through 180 degrees around the U -axis, normal to the nanotube translation vector, is not a symmetry operation, and the SW rotated NT cannot be superimposed onto the original one by any rototranslational operation. When rotating one of the constituents (e.g., the outer shell) around the U -axis, one obtains an inversed DW NT structure, which is different from the “straight” structure initially constructed by the folding procedure. If the U -axis belongs to the one of existing (common) mirror planes σ_h or σ_v , the total symmetry of DW NT

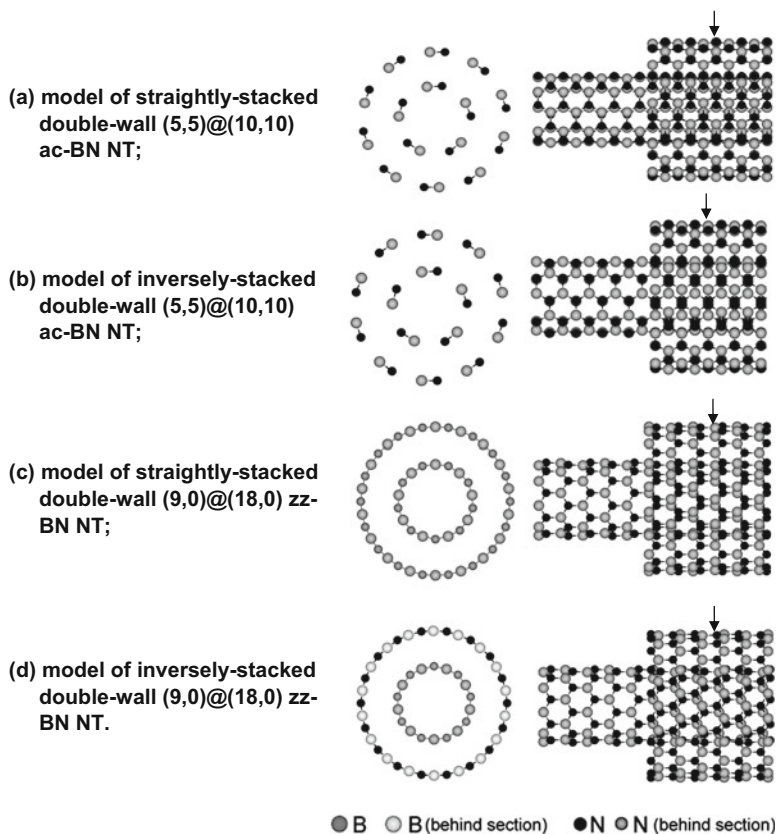


Fig. 13.9 Cross sections and lateral images of hexagonal DWBN NTs (left and right parts of models a–d, respectively) corresponding to optimized diameters for ac and zz chiralities. For zz-DW BN NTs (the models c and d), the atoms of the nearest ring behind the cross section are shown as half-shaded balls. The arrows above each lateral image show the directions of the cross sections. For viewing convenience, the lateral images of the inner shells of the nanotubes are shown as twice as long as those of the outer shells

is unaffected. To satisfy this condition in the case of BN NTs, the U -axis should pass through the BN hexagon center (in particular, this axis can coincide with x). As shown in Fig. 13.9, if one SW NT constituent rotates through 180 around the U -axis (“inversed” DW NT structure), its B and N atoms are permuted, which is not the case with the “straight” DW NT structure. For TiO₂ DW NT, the U -axis should pass through the Ti atom and can coincide with the x -axis.

First we consider here the structural and electronic properties of hexagonal DW BN nanotubes, basing on the results obtained in [1124].

For double-wall boron nitride nanotubes with armchair and zigzag chiralities, we consider two mutual orientations of the chiral and translation vectors of the constituent shells: the coinciding and the opposite (i.e., straight and inversed configurations, respectively). For the ac chirality of DW NTs, the cross sections

Table 13.14 The structural and electronic properties of optimized DW BN NTs

DW NT chirality indices	Initial ΔR_{NT} Å	Optimized ΔR_{NT} Å	Initial $D_{\text{NT}}^{\text{in}}$ Å	Optimized $D_{\text{NT}}^{\text{in}}$ Å	E_{relaxed} (eV) per BN formula unit	E_{bind} (kJ/mol)	Bandgap $\Delta \varepsilon_{\text{gap}}^*$ (eV)
Straight (n1,n1)@(n2,n2) nanotubes, Fig. 13.9a							
(4,4)@(8,8)	2.77	2.93	5.49	5.40	−0.030	−1.86	5.84 ⁱ
(4,4)@(9,9)	3.46	3.46	5.49	5.48	−0.02	0.66	5.95 ⁱ
(5,5)@(10,10)	3.46	3.47	6.88	6.88	−0.019	0.67	6.29 ⁱ
(6,6)@(12,12)	4.15	4.13	8.26	8.28	−0.0002	0.24	6.47 ⁱ
(9,9)@(18,18)	6.13	6.21	12.41	12.41	−0.0001	0.001	6.71 ⁱ
Straight (n1,0)@(n2,0) nanotubes with B(N)–B(N) pairs of rings in cross sections, Fig. 13.9c							
(7,0)@(14,0)	2.79	2.92	5.59	5.50	−0.065	−2.34	4.65 ^d
(8,0)@(16,0)	3.18	3.21	6.38	6.37	−0.039	0.51	5.28 ^d
(9,0)@(18,0)	3.58	3.58	7.18	7.18	−0.018	0.58	5.43 ^d
(10,0)@(20,0)	3.98	3.96	7.97	7.99	−0.0001	0.33	5.72 ^d
(12,0)@(24,0)	4.78	4.77	9.56	9.56	−0.0001	0.001	6.13 ^d
Inversed (n1,0)@(n2,0) nanotubes with N(B)–B(N) pairs of rings in cross sections, Fig. 13.9d							
(6,0)@(12,0)	2.39	2.69	4.79	4.65	−0.224	−7.38	4.81 ^d
(7,0)@(14,0)	2.79	2.95	5.59	5.51	−0.054	−1.34	5.11 ^d
(8,0)@(16,0)	3.18	3.26	6.38	6.36	−0.030	0.50	5.31 ^d
(9,0)@(18,0)	3.58	3.61	7.18	7.19	−0.028	0.68	5.51 ^d
(10,0)@(20,0)	3.98	3.99	7.97	7.99	−0.017	0.37	5.74 ^d
(12,0)@(24,0)	4.78	4.80	9.56	9.57	−0.014	0.001	6.13 ^d

* Indirect and direct gaps are superscripted as ⁱ and ^d, respectively

of the inner and outer shells contain pairs of the B and N atoms (B–N bonds) in the corresponding rings (see Fig. 13.9a,b), which make each of them electrostatically neutral. The difference of energies between ac-DW BN NTs with the same chirality indices and the straight versus inversed orientations of chiral vectors was found to be negligible (about 10^{−4} eV per formula unit). For the zz chirality, both the straight configuration, that is, the outer B(N) ring across the internal B(N) ring (Fig. 13.9c), and the inversed configuration, that is, the N(B) across the B(N) (Fig. 13.9d), were considered, since the corresponding energy difference between them is noticeable (Table 13.14). Obviously, from the electrostatic point of view, the inversed configuration should be energetically more favorable (i.e., the positively charged ring of one shell is the nearest neighbor to the negatively charged ring of another shell, although in-wall B–N interactions are certainly stronger than those between the walls). A similar conclusion was earlier drawn in [1151].

The stability of DW BN NTs depends mainly on the interwall distance, that is, the difference between the radii of the constituent shells ΔR and the diameter of the inner shell D^{in} [1149, 1151, 1154].

Table 13.15 Ionic charges (q) and bond populations (p) for DW BN NTs

Nanotube configuration vs. charge plot in Fig. 13.10	Outer shell		Inner shell		Intershell bond populations		
	q_B^a (e)	P_{B-N}^b (e)	q_B^a (e)	P_{B-N}^b (e)	p_{B-N}^c (e)	p_{B-B}^c (e)	p_{N-N}^c (e)
ac-(5,5)@(10,10) - a)	1.012	0.640	1.010	0.694	0.008 ^d	0.004	−0.004
ac-(9,9)@(18,18) - b)	0.999	0.616	1.010	0.648	0	0	0
zz-s-(9,0)@(18,0) - c)	1.014	0.622	1.010	0.656	0.004 ^e	0.002	−0.002
zz-s-(12,0)@(24,0) - d)	1.003	0.618	1.013	0.648	0	0	0
zz-i-(9,0)@(18,0) - e)	1.021	0.620	1.013	0.656	0.004 ^e	0.002	−0.002
zz-i-(12,0)@(24,0) - f)	1.003	0.618	1.013	0.648	0	0	0

^aEffective charge q_{O-out} of external shell layer (Fig. 13.9)^bEffective charge q_{O-in} of internal shell layer (Fig. 13.9)^cAveraged in-wall Ti–O bond population^dIntegrated intershell bond population for ac-(5,5)@(10,10) BN NT achieves 0.080 e per ring (Fig. 13.9)^eIntegrated intershell bond population for zz-(9,0)@(18,0) BN NT achieves 0.072 e per ring (Fig. 13.9)

The binding energy E_{bind} between the constituent shells of a double-wall nanotube was chosen as a criterion for nanotube stability; see Eq. (13.13):

$$-E_{\text{bind}}(D_{\text{NT}}^{\text{in}}@D_{\text{NT}}^{\text{out}}) = E_{\text{tot}}(D_{\text{NT}}^{\text{in}}@D_{\text{NT}}^{\text{out}}) - E_{\text{tot}}(D_{\text{NT}}^{\text{in}}) - E_{\text{tot}}(D_{\text{NT}}^{\text{out}}) \quad (13.13)$$

where E_{tot} is the calculated total energy of the DW NT and its constituent SW NTs with optimized structure. Also estimated were the relaxation energies E_{relax} (the difference between the total energies of the DW NT before and after geometry optimization) which are usually large for the small values of ΔR_{NT} and $D_{\text{NT}}^{\text{in}}$. The main results of the calculations of the DW BN NTs are given in Table 13.14 and Table 13.15.

Unlike DW BN NTs, *ab initio* simulations on double-wall titania nanotubes are few. Tables 13.15–13.17 present the results of the first *ab initio* LCAO calculations [1124] on titania DW nanotubes. Owing to the electroneutrality of each O–Ti–O shell of DW TiO₂ NTs, the interwall polarization effects in DW TiO₂ NTs are much less noticeable than in zz-DW BN NTs. This is why only straight configurations for both ac and zz chiralities of double-wall titania nanotubes with hexagonal morphology were considered in [1124]. In much the same way as Table 13.14 for DW BN NTs, Tables 13.16 and 13.17 contain data obtained in the calculations of DW TiO₂ NTs. Combining the latter with the binding energy curves $-E_{\text{bind}}(\Delta R_{\text{NT}})$ for titania nanotubes of both chiralities, one can localize the minima of $-E_{\text{bind}}(D_{\text{NT}})$ functions which correspond to (6,6)@(12,12) and (10,0)@(20,0) configurations with interwall distances 4.6–4.8 Å (ΔR_{NT} is defined as a difference between the radii of middle Ti subshells). Meanwhile, when ΔR_{NT} in DW TiO₂ NTs was reduced below the optimal values (≤ 4.1 – 4.3 Å), structural overstrains were observed, markedly larger as compared to DW BN NTs. This is especially true for ac nanotubes of titania (4,4)@(8,8), (6,6)@(10,10), (5,5)@(10,10), and (6,6)@(11,11),

Table 13.16 The structural and electronic properties of optimized DW TiO₂ NTs

DW NT chirality indices	Initial ΔR_{NT} Å	Optimized ΔR_{NT} Å	Initial $D_{\text{NT}}^{\text{in}}$ Å	Optimized $D_{\text{NT}}^{\text{in}}$ Å	E_{relaxed} (eV) per TiO ₂	E_{bind} (kJ/mol) formula unit	Bandgap $\Delta \varepsilon_{\text{gap}}^{\text{a}}$ (eV)
<i>(n1, n1)@(n2, n2)</i> nanotubes							
(6,6)@(12,12)	4.84	4.76	10.06	10.13	−0.07	1.71	3.00 ⁱ
(7,7)@(14,14)	5.66	5.62	11.66	11.69	−0.05	1.08	3.19 ⁱ
(4,4)@(12,12)	6.31	6.30	7.12	7.12	−0.23	0.09	3.90 ⁱ
(8,8)@(16,16)	6.48	6.48	13.26	13.27	−0.02	0.07	3.40 ⁱ
(6,6)@(18,18)	9.73	9.70	10.06	10.09	−0.05	0.001	3.04 ⁱ
(8,8)@(24,24)	13.00	12.99	13.26	13.27	−0.02	0.0001	3.49 ⁱ
<i>(n1, 0)@(n2, 0)</i> nanotubes							
(8,0)@(16,0)	3.61	3.81	8.16	8.25	−0.81	−1.02	2.94 ⁱ
(9,0)@(18,0)	4.10	4.33	9.02	8.94	−0.32	1.59	3.08 ⁱ
(10,0)@(20,0)	4.59	4.62	9.90	9.92	−0.07	2.17	3.21 ^d
(12,0)@(24,0)	5.59	5.48	11.41	11.73	−0.04	0.45	3.31 ^d
(12,0)@(28,0)	7.36	7.10	11.41	11.69	−0.04	0.04	3.35 ^d
(12,0)@(36,0)	9.33	9.34	11.41	11.69	−0.03	0.001	3.38 ^d

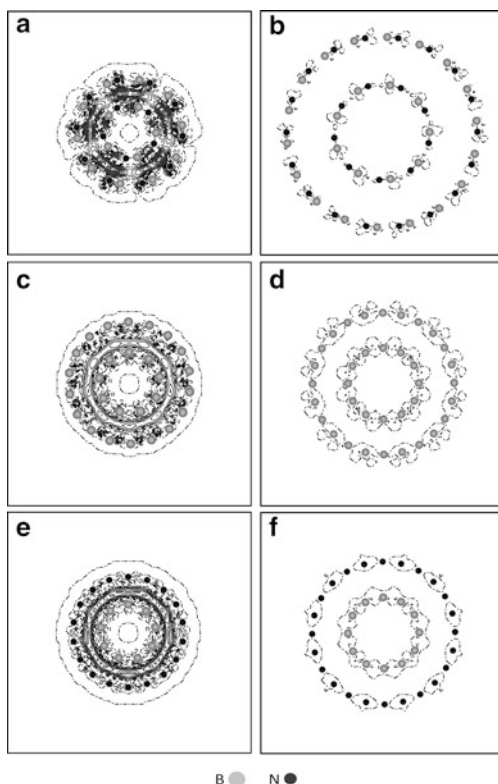
^a Indirect and direct gaps are superscripted as ⁱ and ^d, respectively**Table 13.17** Ionic charges (*q*) and bond populations (*p*) for DW TiO₂ NTs

Nanotube configuration vs. charge plot in Fig. 13.13	Outer shell				Inner shell			
	$q_{\text{O-out}}^{\text{a}}$ (e)	q_{Ti} (e)	$q_{\text{O-in}}^{\text{b}}$ (e)	$p_{\text{Ti-O}}^{\text{c}}$ (e)	$q_{\text{O-out}}^{\text{a}}$ (e)	q_{Ti} (e)	$q_{\text{O-in}}^{\text{b}}$ (e)	$p_{\text{Ti-O}}^{\text{c}}$ (e)
ac-(6,6)@(12,12) - a)	−1.250	2.445	−1.200	0.051	−1.162	2.426	−1.257	0.056
ac-(8,8)@(24,24) - b)	−1.241	2.457	−1.216	0.054	−1.178	2.434	−1.256	0.060
zz-(10,0)@(20,0) - c)	−1.250	2.445	−1.198	0.048	−1.160	2.425	−1.258	0.047
zz-(12,0)@(36,0) - d)	−1.236	2.444	−1.205	0.062	−1.173	2.431	−1.258	0.052

^aEffective charge $q_{\text{O-out}}$ of external shell layer (Fig. 13.11)^bEffective charge $q_{\text{O-in}}$ of internal shell layer (Fig. 13.11)^cAveraged in-wall Ti–O bond population

where geometry optimization has resulted in destruction of double-wall morphology and the formation of complicated nonhexagonal quasi-single-wall morphology. The binding energies estimated per formula unit for the optimal configurations of hexagonal DW NTs are considerably larger for titania as compared to boron nitrides, while the reliefs of minima on $-E_{\text{bind}}(\Delta R_{\text{NT}})$ curves are sharper for the former. Obviously, this is caused by a substantially larger ionic contribution to interwall interaction between the titania SW constituents (Tables 13.15 and 13.17). In both cases, the double-wall nanotube configurations with zz chirality are energetically more favorable as compared to those with ac chirality. Similarly to the DW BN NTs, the small values of ΔR_{NT} and D_{NT} in (Table 13.16) accompanied by the large values of E_{relax} result in the instability of DW TiO₂ NTs, while the large values of ΔR_{NT} correspond to cases when the interaction within the pairs of the constituent

Fig. 13.10 Difference electron density plots $\Delta\rho(r)$ (total electron densities in the perfect DW BN NT minus the sum of these densities in the two constituent SW BN NTs) calculated for the cross sections of nanotubes depicted in Fig. 13.9: (a) (5,5)@(10,10), (b) (9,9)@(18,18), (c) straight (9,0)@(18,0), (d) straight (12,0)@(24,0), (e) inverted (9,0)@(18,0), (f) inverted (12,0)@(24,0). The solid, dashed, and dot-dashed isolines describe positive, negative, and zero values of the difference density, respectively. Isodensity curves are drawn from -0.001 to $+0.001$ e $\text{\AA}^{-3}$ with increments of 0.00004 e $\text{\AA}^{-3}$



SW NTs is almost negligible. Similarly to DW BN NTs, E_{bind} is rather negligible (Table 13.16).

Figure 13.10 shows the electronic charge redistribution difference drawn for both the optimal and increased values of ΔR_{NT} and $D_{\text{NT}}^{\text{in}}$ for double-wall ac- and zz-BN NTs (Fig. 13.9).

For the optimal structures of DW NTs, considerable redistributions of the electronic density can be observed with clearly visible polarization effects, especially around the inner shells. The latter are the largest for the inversely stacked configuration of zz-BN NTs, while the $\Delta\rho(r)$ function for ac-BN NTs is characterized by more pronounced localization effects. For double-wall nanotubes with large interwall distances (Fig. 13.10 b,d,f), the interaction between the outer and inner shells is very weak, which reduces the stability of DW BN NTs. The Mulliken population parameters (Table 13.15) calculated for both chiralities of the optimal and quasi-independent DW BN NT structures qualitatively confirm the results extracted from the drawn electron density redistributions (Fig. 13.10).

The straightly stacked configurations for both ac and zz chiralities of DW TiO₂ NTs with hexagonal morphology (panels a and b of Fig. 13.11, respectively) were calculated in [1124]. Unlike DW BN NTs, no permutation of Ti and O atoms occurs

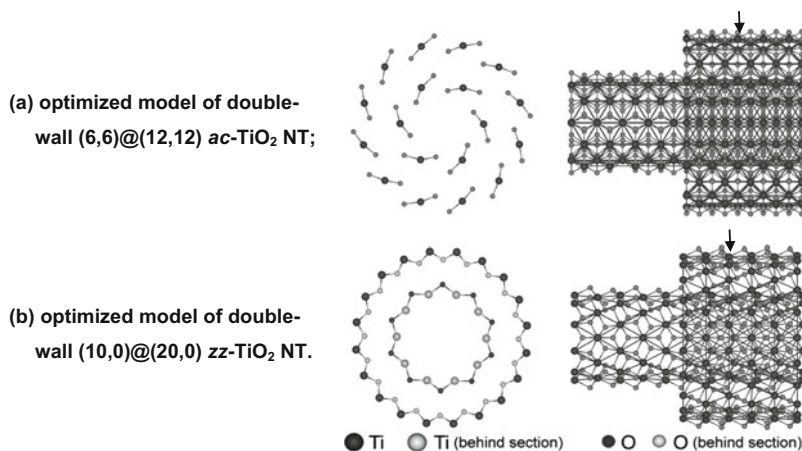


Fig. 13.11 Cross sections and lateral images of hexagonal DW TiO₂ NTs (i.e., left and right parts of models a and b, respectively) corresponding to optimized diameters for armchair and zigzag chiralities. For *zz*-DW TiO₂ NTs (model b), the atoms of the nearest ring behind the cross section are shown as *half-shaded balls*. For the description of the graphical details of models, see the clarification in the caption of Fig. 13.9

in the case of inverted configurations. In *ac*-DW TiO₂ NTs, such an inversion means the angular reorientation of O–Ti–O shells (Fig. 13.11a), which does not cause any noticeable rearrangement of the intershell bonding. A similar conclusion can be drawn also for the *zz*-DW TiO₂ NT, although the interwall polarization causes the Δz shift when the cross section of the nanotube contains Ti and O atoms which belong to different shells (Fig. 13.11b). Analogously to DW BN NTs (Table 13.14 and Figs. 13.9 and 13.10), similar calculations for DW TiO₂ NTs were made in [1124]. Their results are presented in Tables 13.16 and 13.17.

The construction of the binding energy curves for titania nanotubes of both chiralities allows one to localize the minima of $-E_{\text{bind}}(\Delta R_{\text{NT}})$ functions (Fig. 13.12) which correspond to (6,6)@(12,12) and (10,0)@(20,0) double-wall configurations of DW TiO₂ NTs with interwall distances 4.6–4.8 Å (ΔR_{NT} is defined as a difference between the radii of middle Ti subshells). Meanwhile, when reducing Å (ΔR_{NT} in DW TiO₂ (≤ 4.1 –4.3 Å) NTs below the optimal values one observes structural overstrains, markedly larger as compared to DW BN NTs. This is especially true for titania *ac* nanotubes, (4,4)@(8,8), (6,6)@(10,10), (5,5)@(10,10), and (6,6)@(11,11), where geometry optimization resulted in the destruction of double-wall morphology and the formation of complicated nonhexagonal quasi-single-wall morphology. It was found in [1124] that the binding energies estimated per formula unit for the optimal configurations of hexagonal DW NTs are considerably larger for titania as compared to boron nitrides. Obviously, this is caused by a substantially larger ionic contribution to the interwall interaction between the titania SW constituents (Tables 13.15 and 13.17). In both cases, the double-wall nanotube configurations

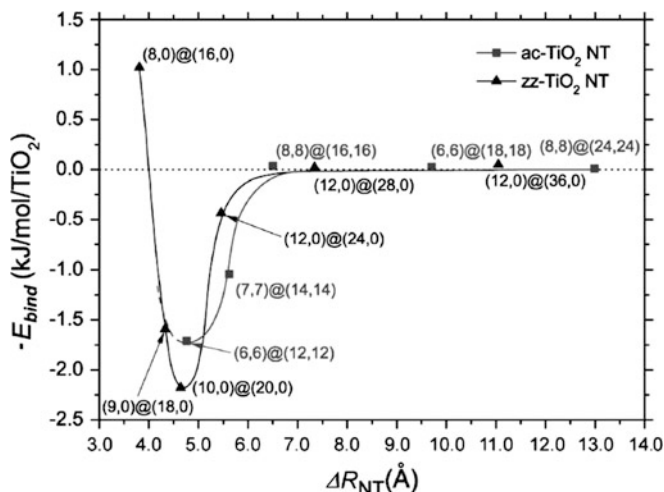


Fig. 13.12 Binding energies E_{bind} versus ΔR_{NT} for the two sets of DW TiO₂ NTs with ac and zz chiralities. Spline treatment of the curves was performed to make them smooth

with zz chirality are energetically more favorable as compared to those with ac chirality. Similarly to DW BN NTs, the small values of ΔR_{NT} and D_{NT}^{in} (Table 13.16) accompanied by the large values of E_{relax} result in the instability of DW TiO₂ NTs, while the large values of ΔR_{NT} correspond to an almost neglecting interaction within pairs of constituent SW NTs. Similarly to DW BN NTs, E_{bind} for titania nanotubes is sensitive to ΔR_{NT} , while the influence of D_{NT}^{in} on E_{bind} is rather negligible (Table 13.16).

The comparison of the difference electronic charge redistributions drawn for both optimal and increased values of ΔR_{NT} within ac- and zz-DW NTs (both BN and TiO₂) [1124] demonstrates higher electron density localization within the latter (especially for armchair-type nanotubes), while the comparison of the results presented in Table 13.15 and Table 13.17 shows a noticeably higher bond ionicity in DW TiO₂ NTs. The bond populations between the shells in DW TiO₂ NTs were found to be close to zero. For large ΔR_{NT} in double-wall titania nanotubes (Fig. 13.6), the intershell interaction again becomes weak again, that is, the stability of these DW TiO₂ NTs is low enough, analogously to DW BN NTs.

Unlike boron nitride nanotubes, the difference between the values of the bandgap for double-wall and single-wall TiO₂ NTs is considerably larger. The additional difference between them occurs for the small values of ΔR_{NT} ; the bandgaps of zz-DW TiO₂ NTs are indirect, while for zz-DW BN NTs, these bandgaps are direct for all configurations. This can be explained by a substantially smaller stability of DW TiO₂ NTs with reduced values of ΔR_{NT} . Moreover, when both the inner D_{NT} and ΔR_{NT} increase the bandgaps of double-wall titania nanotubes are still too far from the bandgap limit of TiO₂(111) three-layer slab (4.89 eV) [1123]. However, the

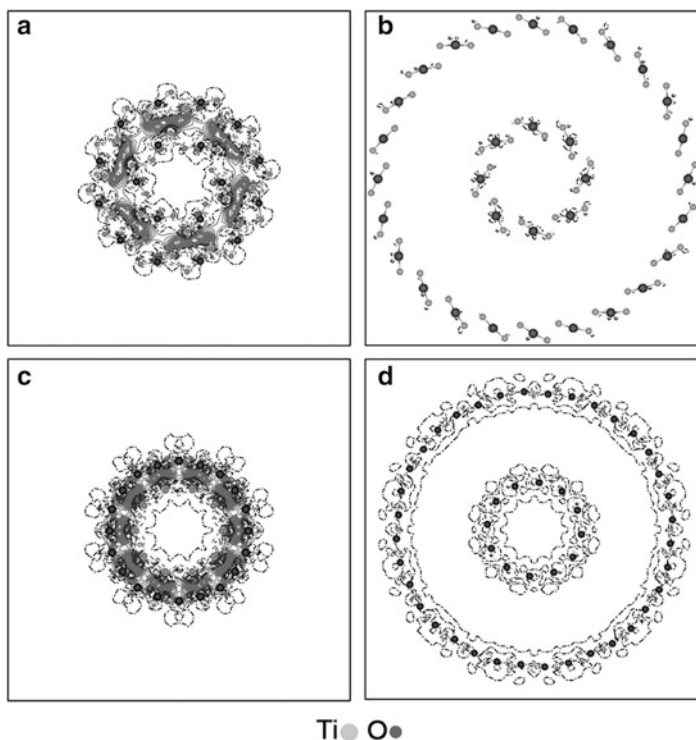


Fig. 13.13 Difference electron density plots $\Delta\rho(r)$ of DW TiO₂ NTs calculated for the cross sections of nanotubes depicted in Fig. 13.11: (a) (6,6)@(12,12), (b) (8,8)@(24,24), (c) (10,0)@(20,0), (d) (12,0)@(36,0). For technical and graphical details, see the caption of Fig. 13.10

dependence of bandgaps on both ΔR_{NT} and inner D_{NT} is similar for both DW BN and TiO₂ NTs, that is, the bandgap is the most dependent on the diameter of inner shell. The Mulliken population analysis shows that O(2p) states prevail near the top of the valence band while Ti(3d) states are mainly distributed near the bottom of the conduction band.

The comparison of the total energies between optimal DW TiO₂ NTs with hexagonal fluorite-type morphology and SW TiO₂ NTs with anatase-type centered rectangular morphology [1122] containing the same number of atoms per nanotube unit cell allows one to make the following conclusions. For similar chiralities, one observes energetic preference of the latter: (a) the energy gain for (−9,9) SW NT versus (6,6)@(12,12) DW NT with the number of atoms equal to 108 has been found to be 0.09 eV per TiO₂ formula unit and (b) an analogous energy gain for 180-atomic unit cells of SW and DW nanotubes with chiralities (15,15) and (10,0)@(20,0) achieves 0.17 eV per TiO₂ formula unit. Thus, the growth of anatase-type NTs is preferable.

13.4 LCAO Calculations of TiO₂ Nanotubes with Rectangular Morphology

The morphology of titania nanotubes is governed by the structure of atomic layers in the bulk phases, and it is much more complicated than that of carbon and BN nanotubes. The distance between two six-layer slabs (1.2 Å) is two times larger than that between the neighboring three-layer slabs (0.6 Å) used in the calculations of the simplified hexagonal three-layer model of TiO₂ nanotubes considered above. A more realistic six-layer titania nanotube model was used in [1116, 1118, 1140]. The model uses six atomic planes of the (101) anatase slab (three Ti- and three O-planes), and the slab obtained belongs to the rectangular lattice; see Fig. 13.20. As follows from Eq. (13.12), there are restrictions on the NT chiralities compatible with the translational symmetry.

The bulk anatase structure is described by the space group $I4_1/amd$ with four TiO₂ formula units in the tetragonal (conventional) unit cell with the edges a and c . Figure 13.1 shows a (1 0 1) slab consisting of 6 atomic planes (four oxygen and two titanium planes). The 2D translation symmetry of the slab corresponds to the centered rectangular lattice with 12 atoms in the conventional unit cell with the edges a and $\sqrt{a^2 + c^2}$. The nanotubes $(-n, n)$ and (n, n) are constructed by rolling an anatase (1 0 1) sheet along the $(\bar{1}01)$ and (010) directions, respectively. The 1D line symmetry groups of the $(-n, n)$ and (n, n) titania nanotubes contain $(2n)_n$ screw axis. These axes are oriented along the tube one-dimensional translation vector $\mathbf{a}$. Just after the rolling up, the reflection planes contain $\mathbf{a}$ for the $(-n, n)$ nanotubes and are perpendicular to $\mathbf{a}$ for the (n, n) ones. During nanotube structure relaxation, new symmetry elements (reflection planes and twofold axes) can appear.

Table 13.18 gives the line symmetry groups of SW TiO₂ NTs, rolled from two-periodic titania layers. Figure 13.11 shows the ways of constructing of SW nanotubes for three types of titania sheets: one 3-layered with hexagonal morphology and two 6-layered ones with rectangular morphology. The 3-layer model of the anatase (101) slab considered in the preceding section consists of three atomic layers (O–Ti–O), its structural optimization results in the formation of a fluorite-type (111) slab [1138, 1141] whose symmetry can be attributed to the layer 2D group $72(P\bar{3}m1)$. It is the same for the 3-layer slab with both anatase and fluorite structures, although the space symmetry of the fluorite TiO₂ bulk crystal is described by cubic space group $225(Fm\bar{3}m)$. In the case of the 6-layer model (O–O–Ti–Ti–O–O), all the six atoms of the bulk primitive unit cell are included, and both centered and primitive rectangular lattices have to be considered. The 12-layer (O–O–Ti–Ti–O–O–O–O–Ti–Ti–O–O) model contains two quasi-separated 6-layer slabs. The layer group $18(C2/m11)$ with a centered rectangular lattice describes the symmetry of both 6- and 12-layer slabs. The bulk titania with lepidocrocite structure can be attributed to the orthorhombic space group 63 (Cmcm). The 6-layer model of the lepidocrocite (010) slab consists of six atomic layers (O–Ti–O–O–Ti–O)[1139]. The layer group $46(Pmmn)$ with a primitive rectangular lattice describes its symmetry.

Table 13.18 Line symmetry groups of SW TiO₂ NTs, rolled from two-periodic titania layers

Object	Space group for C, BN, and TiO ₂ bulk	Layer	Layer group	Line groups for special chiralities ^a	P _I	Line groups for general chiralities (n ₁ , n ₂)
3-layer hexagonal	225 <i>Fm$\bar{3}m$</i>	(111)	72(<i>P$\bar{3}m$1</i>)	4 <i>h</i> (2 <i>n</i>) _n / <i>m</i> 8 <i>g</i> (2 <i>n</i>) _n <i>mc</i>	<i>C</i> _{2<i>nh</i>} <i>C</i> _{2<i>nv</i>}	1 <i>n_q</i> (<i>C_q</i>)
6-layer centered rectangular	141 <i>I</i> 4 ₁ / <i>amd</i>	(101)	18(<i>C</i> 2/ <i>m</i> 11)	4 <i>e</i> (2 <i>n</i>) _n / <i>m</i> 8 <i>d</i> (2 <i>n</i>) _n <i>mc</i>	<i>C</i> _{2<i>nh</i>} <i>C</i> _{2<i>nv</i>}	1 <i>n_q</i> (<i>C_q</i>)
12-layer centered rectangular	141 <i>I</i> 4 ₁ / <i>amd</i>	(101)	18(<i>C</i> 2/ <i>m</i> 11)	4 <i>e</i> (2 <i>n</i>) _n / <i>m</i> 8 <i>d</i> (2 <i>n</i>) _n <i>mc</i>	<i>C</i> _{2<i>nh</i>} <i>C</i> _{2<i>nv</i>}	1 <i>n_q</i> (<i>C_q</i>)
6-layer primitive rectangular	63 <i>Cmcm</i>	(010)	46(<i>Pmmn</i>)	11 <i>c</i> <i>n</i> / <i>mmm</i> ^b (2 <i>n</i>)2 <i>m</i> ^c	<i>D</i> _{<i>nh</i>}	5 <i>n_q</i> 22(<i>D_q</i>)

^a Special chiralities: *c* - (*n*, 0), (0, *n*); *d* - (*n*, *n*); *e* - (-*n*, *n*); *g* - (*n*, 0), (0, *n*), (-*n*, *n*); *h* - (*n*, *n*), (-*n*, 2*n*), (-2*n*, *n*); *i* - (*n*, 0), (0, *n*), (-*n*, *n*), (*n*, *n*), (-*n*, 2*n*), (-2*n*, *n*)

^b For even *n*

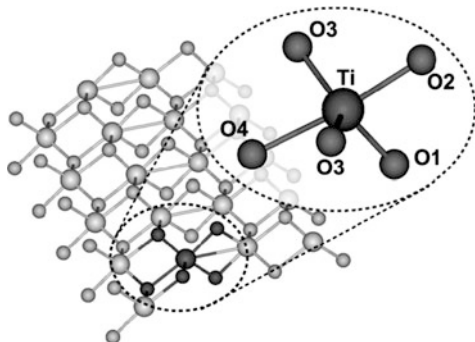
^c For odd *n*

Table 13.18 gives the line symmetry groups of SW TiO₂ NTs, rolled from two-periodic titania slabs.

The first-principle calculations of six-layer TiO₂ NTs were made in [1116, 1118, 1139, 1140]. As the number of atoms in the six plane model of the TiO₂ nanotube quickly increases with increasing diameter, the ab initio calculations are very time consuming for the structural optimization. Therefore, in [1140], the molecular mechanics-based calculations were applied to obtain the optimized nanotube structure, while electronic band structures were obtained by performing DFT (LDA) calculations. As in all the plane wave calculations, the three-periodic nanotube model was used in [1140]: a tetragonal supercell with the lattice parameter *a* much larger than the nanotube translation periodicity was adopted, but the result dependence on the parameter *a* was not investigated. The two types (-*n*, *n*) and (*n*, *n*) of titania nanotubes (called in [1140] A and B types, respectively) were studied. It was found that A nanotubes are energetically preferable to the B nanotubes. According to [1140], the bandgap of the A nanotube was reduced by 0.60 eV as the tube diameter decreases from 12 to 5 Å. The first hybrid HF/DFT LCAO calculations of both the structure and electronic properties of the TiO₂ nanotube obtained by rolling of six-layer (1 0 1) anatase slab were made in [1116, 1118]. In the LCAO calculations of TiO₂ NTs, no artificial 3D periodicity is necessary.

We now proceed to discuss the results of the first-principles hybrid HF–DFT LCAO calculations [1118, 1122] on the 6- and 12-layer models of the TiO₂ NTs with rectangular morphology. The CRYSTAL09 computer code [953] was used. As in the three-layer model calculations [1123, 1124] of TiO₂ NTs with hexagonal morphology, the small-core pseudopotential [884] of the Ti atom was

Fig. 13.14 Fivefold coordination for Ti atoms in six-layer centered rectangular titania sheets



used ($3s$ -, $3p$ -, $3d$ -, and $4s$ -electrons were taken as valence electrons), while the all-electron BS for the O atom were taken from [1144].

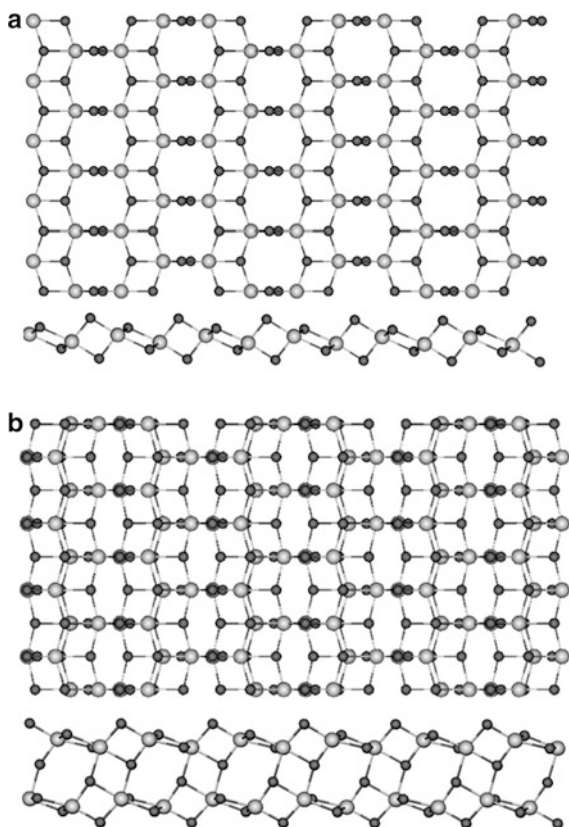
The diffuse exponents of valence s , p , and d orbitals were optimized for the stable anatase phase of the bulk titania. Its atomic and electronic properties were reproduced in the good agreement with the experiment (the experimental values are given in brackets): the lattice parameters $a = 3.784 \text{ \AA}$ (3.782 $\text{\AA}$) and $c = 9.508 \text{ \AA}$ (9.502 $\text{\AA}$) and the dimensionless parameter for the relative position of the oxygen atom $u = 0.2074$ (0.2080); the values of the energy gap are reproduced worse, because of being overestimated: 4.0 eV versus 3.2 eV. In any case, these results for the bulk titania (anatase) agree with the experimental data better than those given in [1147] for both plane wave (PW) and the LCAO calculations when the different exchange–correlation potentials were used. A certain improvement of the substantially underestimated values of the energy gap for the bulk anatase in the DFT PW calculations was achieved recently [1142] using the LDA + U method (2.7 eV).

The structures of 6- and 12-layer anatase (101) slabs (see Fig. 13.14) were optimized in [1118, 1122], and their properties were calculated. Both 6- and 12-layer anatase (101) slabs keep their initial symmetry after structural optimization, although their lattice parameters differ from those in the bulk; see Table 13.20.

The six-layer titania sheets with anatase-type (101) structure can be rolled up to 6-layer titania SW NTs with (a) $(-n, n)$ chirality and (b) (n, n) chirality. Figure 13.16a shows the optimized structures of the selected 6-layer nanotubes of both chiralities. A specific feature of these six-layer titania sheets and nanotubes is that both Ti sublayers are rearranged in the middle between the surfaces of both the sheets and nanotubes, see Figs. 13.15a and 13.16a, that is, their optimized structure is O–O–Ti–Ti–O–O which is different from O–Ti–O–O–Ti–O owing to the sequence of TiO_2 formula units in the bulk anatase structure.

Table 13.21 presents the results obtained after the structural optimization of 6-layer TiO_2 NTs with (a) $(-n, n)$ chirality (for $n = 3, 4, 6, 9, 12$) and (b) (n, n) chirality (for $n = 6, 10, 15, 20, 24$). One of the main parameters of the nanotube stability, that is, the strain energy E_{strain} , is defined as a difference between the total energies of the optimized nanotube E_{NT} and the corresponding slab before

Fig. 13.15 Models of stoichiometric (101) titania sheets of different thickness optimized from the corresponding slabs with initial geometry of bulk anatase (lateral and cross-section images): (a) 6-layer slab (thickness 0.24 nm); (b) 12-layer slab (thickness 0.58 nm)



rolling up E_{slab} , with regard to the number k of slab unit cells in the nanotube unit cell containing m formula units TiO₂ (measured in kJ/mol per TiO₂ formula unit): $E_{\text{strain}} = (E_{\text{NT}} - kE_{\text{slab}})/m$. Obviously, the number of atoms per surface unit in $(-n, n)$ nanotubes is markedly smaller than that in (n, n) NTs of the same diameter; thus, the latter can be calculated faster. For the small diameter D_{NT} (low chirality indices), the absolute values of both E_{relax} and E_{strain} are large enough, and trying to reduce these diameters even more, one faces an enhanced instability of NTs. For example, the convergence of calculations on (4,4) nanotubes has been found to be rather poor. Since hypothetical nanotubes with an infinite diameter should coincide with sheets of the same thickness, a consequent growth of the NT diameters leads to a substantial decrease in both relaxation and strain energies (down to zero at infinity), whereas the values of other properties (Table 13.21) approach those for the 6-layer titania slab with hexagonal structure (Table 13.20).

To analyze the dependence of E_{strain} and the energy gap on the diameter of six-layer TiO₂ NTs, the sufficiently large range of nanotube diameters, from 0.5 to 4.0 nm, with the number of atoms per NT unit cell increased from 36 up to 288 was considered in [1118]. Two curves $E_{\text{strain}}(D_{\text{NT}})$ shown in Fig. 13.17 demonstrate

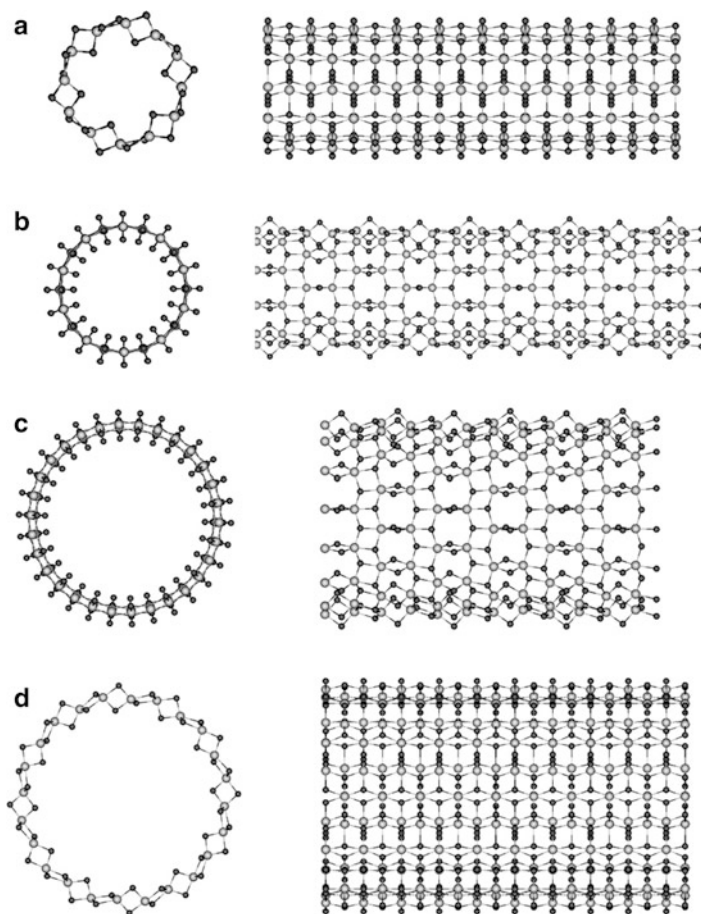


Fig. 13.16 Atop (lateral) and across (cross-section) views of 6-layered anatase-like SW TiO₂ nanotubes for different chiralities: (a)(-3, 3), (b)(10,10),(15,15),(-6, 6)

that the strain energy of six-layer NTs with $(-n, n)$ chirality is smaller than that of (n, n) NTs of a similar diameter, that is, the former are more stable energetically. This difference remains noticeable for nanotubes with diameters ≤ 30 Å. When the diameters of nanotubes increase to 40 Å, the strain energies decrease and approach one another.

For six-layer titania nanotubes of both chiralities, $\Delta E_{\text{gap}}(D_{\text{NT}})$ curves possess maxima at the diameter range 13–17 Å (Fig. 13.18). For larger values of D_{NT} , both the relaxation and strain energies of TiO₂ nanotubes substantially decrease, while their bandgaps asymptotically approach that for the corresponding 2D slab (Table 13.20).

Table 13.19 presents the comparison of the results of calculations on four pairs of structurally similar TiO₂ nanotubes. The optimized values of D_{NT} in each pair of these NTs were selected to be very (the relative difference of the diameters

Fig. 13.17 Strain energies E_{strain} versus D_{NT} for the two sets of six-layer SW TiO₂ NTs with various chiralities

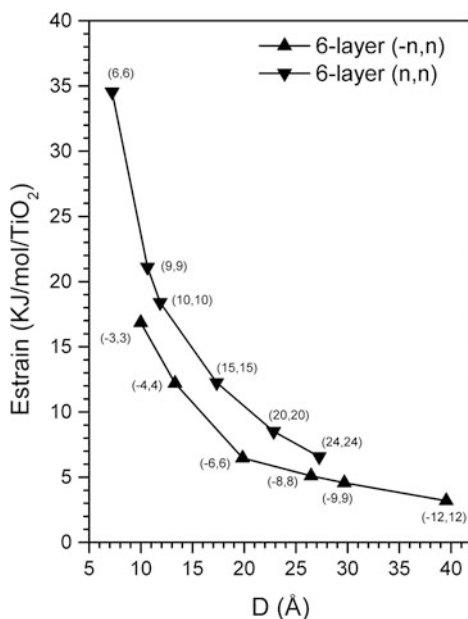
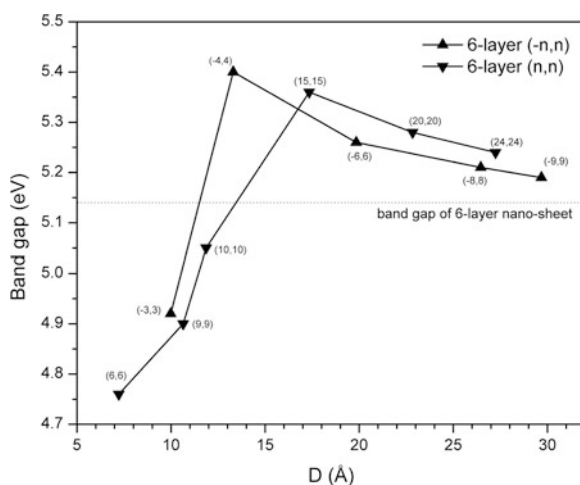


Fig. 13.18 Bandgaps versus D_{NT} for the two sets of six-layer SW TiO₂ NTs with various chiralities



in different pairs has varied from 0.57% to 1.34%). The structural compatibility of all the four pairs can be explained by their belonging to the same line groups (Table 13.18), that is, the chiralities of 3-layer (n, n) and 6-layer $(-n, n)$ nanotubes can be described by the same line group $(2n)_n/m$, whereas the line group $(2n)_nmc$ corresponds to both 3-layer $(n, 0)$ and 6-layer (n, n) NTs. Alongside the proximity

of diameters, this symmetry factor makes reasonable the direct comparison of the structural and electronic properties in each pair of these nanotubes. One can

Table 13.19 The structural and electronic properties of four pairs of symmetry-compatible TiO₂ NTs^a

Pairs of NTs with equal diameters	N_a	D_{NT} ,	l_{NT} ,	h_{NT} ,	d_{TiO} , Å				q_{Ti} ,	E_{relax} ,	E_{strain} ,	ΔE_{gap} ,
		Å	Å	Å	Ti-O1	Ti-O2	Ti-O3	Ti-O4	e	eV/TiO ₂	kJ/mol per TiO ₂	eV
(2n)/m group												
3-layer (6,6)	36	10.06	2.99	1.86	1.89	1.94	2.00	2.05	2.42	−0.09	46.18	4.66 ⁽ⁱ⁾
6-layer (−3, 3)	36	9.98	3.66	2.45	1.795	1.86	1.925	2.025	2.28	−0.82	16.86	4.92 ⁽ⁱ⁾
(2n)nmc group												
3-layer (12,0)	72	11.70	5.10	1.88	1.915	1.945	1.96	2.03	2.43	−0.09	33.71	4.70 ⁽ⁱ⁾
6-layer (10,10)	120	11.85	10.39	2.46	1.80	1.835	1.945	2.02	2.27	−0.45	18.39	5.05 ^(d)
(2n)nmc group												
3-layer (18,0)	108	17.23	5.12	1.90	1.935	1.95	1.965	1.965	2.44	−0.05	14.93	4.75 ⁽ⁱ⁾
6-layer (15,15)	180	17.33	10.33	2.43	1.785	1.87	1.92	2.01	2.27	−0.14	12.25	5.36 ⁽ⁱ⁾
(2n)/m group												
3-layer (12,12)	72	19.73	2.97	1.91	1.935	1.95	1.98	1.995	2.44	−0.04	11.26	4.77 ⁽ⁱ⁾
6-layer (−6, 6)	72	19.84	3.54	2.39	1.765	1.87	1.92	2.11	2.19	−0.14	6.47	5.26 ⁽ⁱ⁾

^aDefinition of values is the same as before

conclude from the data presented in Table 13.19 that in 3- and 6-layer nanotubes with close diameters described by the (2*n*)_{*n*}/*m* symmetry group, the number of atoms per unit cells is the same, whereas the length of the unit cell of the latter is about 20% larger. In the analogous NT pairs described by the (2*n*)_{*n*}*mc* symmetry group the number of atoms per unit cell is larger by about 70% for 6-layer nanotubes, while their lengths are more than twice larger compared to 3-layer NTs. Thus, if one estimates the density of atoms per NT length, it will be larger for 3-layer nanotubes. The 6-layer NT thickness is about 30% larger than that of 3-layer nanotubes for all chiralities. As to Ti–O bond lengths, their deformation is noticeably larger in 6-layer nanotubes, and it is not decreased for *D_{NT}* up to 30 Å, whereas in the 3-layer NTs, the values of *d_{Ti–O}* approach those in the three-layer slab (Table 13.19) much faster. Obviously, this is also true for the convergence of *E_{relax}* with *D_{NT}* increasing (Table 13.20). The chemical nature of the Ti–O bonds in both three- and six-layer titania nanotubes is slightly different. The values of effective charges *q_{Ti}* on titanium atoms presented in Table 13.20 clearly show that the chemical bonding in hexagonal nanotubes is more ionic. On the other hand, the calculated Ti–O bond populations in 6-layer NTs were found to be 2–3 times larger than those in 3-layer slabs achieving 0.16–0.18 e per internal wall bonds, that is, the bonding in the former is more covalent. A series of the calculations for the total and projected densities of states (DOS and PDOS) for the TiO₂ anatase bulk, 3-, 6-, and 12-layer titania sheets were also made in [1122]. It was found that the DoSs of the 6- and 12-layer sheets and the 6-layer nanotube are qualitatively similar to the DOSs of the bulk anatase. When both *D_{NT}* and the number of atoms are increased, the profiles of DOSs and PDOSs become more

Table 13.20 The atomic and electronic structure of TiO₂ bulk versus various slabs

Models of TiO ₂ Bulk and sheets	Lattice parameters		Thickness h_{NT} (Å)	Bond length $d_{\text{Ti-O}}$ ^a (Å)				Effective charge q_{Ti} , ^b e	E_{relax} per TiO ₂ unit, ^c eV	Surface energy E_{surf} , ^d $\Delta\epsilon_{\text{gap}}^{\text{e}}$	
	a	c		Ti – O1	Ti – O2	Ti – O3	Ti – O4			E_{surf} , ^d J/m ²	eV
bulk	3.78	9.51	–	1.935	1.935	1.973	1.973	2.35	–	–	4.09
6-layer	3.51	5.45	2.39	1.75	1.89	1.91	2.05	2.28	–1.09	0.64	5.14
12-layer	3.71	5.46	5.83	1.77	1.83	1.95	2.01	2.30	–0.55	0.67	4.92

^a The corresponding bonds are shown in Fig. 13.14

^b Averaged effective charges q_{O} are twice smaller than q_{Ti} , with the opposite sign

^c E_{relax} is a difference of energies between a slab with “bulk” geometry and that with an optimized structure

^d $E_{\text{surf}}(n) = \frac{1}{2S}(E_n - nE_b)$, where E_n is the total energy of the n -layer slab per primitive surface unit cell, S its area, while E_b is the total energy per primitive bulk unit cell

^e All bandgaps considered in this table are indirect

complicated, since the number of one-electron states increases. The total density of states projected on different atomic states implies that the states of the highest valence band (VB) mainly arise from the 2p states of oxygen atoms, while those of the lowest conduction band (CB) come from the 3d states of Ti atoms. In 6-layer nanotubes, the contributions of O and Ti states in CB and VB states are found to be larger than in 3-layer nanotubes. It means that the O(2p) – Ti(3d) bond hybridization is more pronounced at PDOSs calculated for the equilibrium six-layer TiO₂ nanotube structures, that is, their covalent bonding is stronger.

The twelve-layer single-walled TiO₂ nanotubes with rectangular morphology were also simulated in [1118]. The middle of the 12-layer TiO₂ slab consists of two sublayers containing oxygen atoms (Fig. 13.15a), and when the single-walled titania nanotube is obtained by rolling up this twelve-layer sheet, its thickness is about 2.5 times larger than that of the six-layer TiO₂ nanotube. As a result, the atomic structure of the internal wall surface of this 12-layer NT is overstrained even for the moderate values of D_{NT} . A comparison of images for both six- and twelve-layer NTs with the same (–6, 6) and (12, 12) chiralities (Fig. 13.19) clearly shows quite small geometry relaxation of the former and a drastic change of morphology of the latter, which cannot be optimized at all, due to a divergence of the SCF calculations after several steps of geometry optimization.

This effect can be also illustrated by a drastic difference between the calculated strain energies E_{strain} for six- and twelve-layer SW TiO₂ NTs with the initial geometry after rolling up the corresponding slabs, for (–6, 6) and (12, 12) chiralities: 23.76 and 41.78 versus 224.04 and 498.62 kJ/mol per TiO₂ formula unit, respectively. Thus, one can predict that for 12-layer titania nanotubes, the more preferable morphology has to be not SW but the double-walled (DW) NT consisting of a pair of six-layer nanotubes of different diameters and chirality indices.

It is seen that ab initio LCAO calculations using the hybrid PBE0 Hamiltonian allow one to perform the analysis of the atomic and electronic structure of TiO₂ sheets, as well as nanotubes simulated using different models. It was found in [1122] that the structural optimization of the 3-layer slab results in a spontaneous

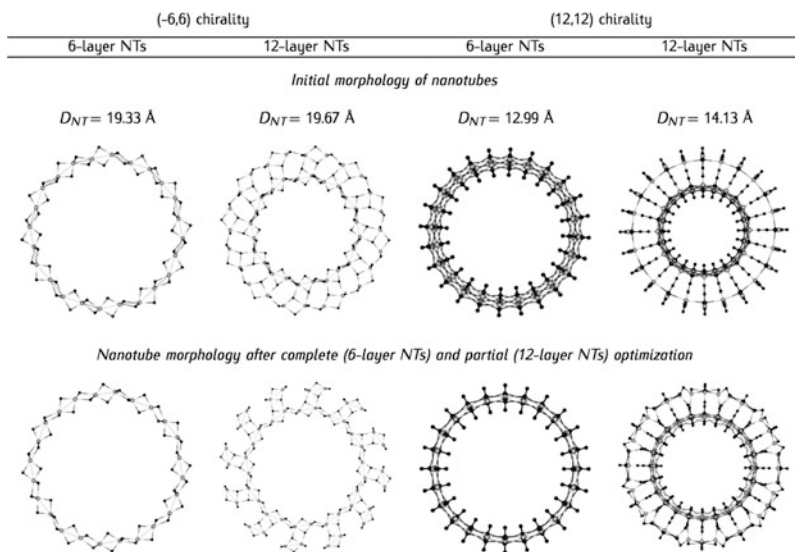


Fig. 13.19 Cross sections of 6- and 12-layer SW TiO₂ NTs with (-6; 6) and (12;12) chiralities, respectively (D_{NT} for nanotubes with initial geometry are defined as described in Table 13.21)

(barrier-less) reconstruction into the hexagonal (111) fluorite structure. The structural optimization of three- and six-layer single-walled titania nanotubes leads to a growth of the NT diameter for all the morphologies considered. Noticeable differences between the calculated properties of 3- and 6-layer TiO₂ sheets and nanotubes were found. First of all, the strain energies of the six-layer nanotubes are smaller than those of the 3-layer NTs of close diameters (for $D_{NT} \leq 20\text{--}25 \text{ \AA}$). The most probable reason for this 6-layer NT energetical stability is that in the six-layer titania sheets and nanotubes with anatase structure both Ti sublayers are positioned in the middle between the surfaces of both the sheets and the nanotubes, that is, their formal bulk structure is O-O-Ti-Ti-O-O. On the other hand, the relaxation energies of 6-layer NTs are larger than those of 3-layer nanotubes (especially for small NT diameters), due to a more complicated structure of the former. The bandgaps of six-layer titania nanotubes (typical semiconductor with $\Delta E_{\text{gap}} \leq 5 \text{ eV}$) are found to be noticeably larger (up to 0.5 eV) as compared to three-layer NTs of the same diameter. When these diameters markedly increase, the nanotube bandgaps asymptotically approach those for 2D slabs of the corresponding thickness.

The chemical nature of the Ti-O bonds in both three- and six-layer titania nanotubes is slightly different: the values of effective charges on titaniums clearly show that the bonding in hexagonal nanotubes is more ionic, while higher Ti-O bond populations in 6-layer NTs (achieving 0.16–0.18 e per bond on internal wall) result in a more covalent bonding.

The strain energies of 6-layer SW TiO₂ NTs decrease with the growth of the nanotube diameter, approaching a minimum for the infinite D_{NT} . ΔE_{gap} curves for

Table 13.21 The structural and electronic properties of six-layer SW TiO₂ NTs (Fig. 13.16)^a

NT chirality indices	N_A	$l_{NT},^b \ D_{NT},^c \ h_{NT}, \ d_{Ti-O}, \text{\AA}$								$q_{Ti}, \ E_{relax},$		$E_{strain},$	$\Delta\epsilon_{gap},^d$
												kJ/mol	
		$\text{\AA}$	$\text{\AA}$	$\text{\AA}$	$\overline{\text{Ti-O1 Ti-O2 Ti-O3 Ti-O4}}$				e	eV/TiO ₂	per TiO ₂	eV	
<i>(-n, n)</i> nanotubes - $(2n)_n/m$ group													
(-3, 3)	36	3.66	9.98	2.45	1.795	1.86	1.925	2.025	2.28	-0.82	16.86	4.92 ⁽ⁱ⁾	
(-4, 4)	48	3.60	13.30	2.41	1.775	1.89	1.94	2.01	2.21	-0.35	12.20	5.40 ⁽ⁱ⁾	
(-6, 6)	72	3.54	19.84	2.39	1.765	1.87	1.92	2.11	2.19	-0.14	6.47	5.26 ⁽ⁱ⁾	
(-9, 9)	108	3.52	29.68	2.39	1.77	1.875	1.91	2.09	2.27	-0.05	4.57	5.19 ⁽ⁱ⁾	
(-12, 12)	144	3.52	39.55	2.39	1.77	1.88	1.90	2.085	2.27	-0.03	3.20	5.17 ⁽ⁱ⁾	
<i>(n, n)</i> nanotubes - $(2n)_{nmc}$ group													
(6,6)	72	10.32	7.22	2.44	1.79	1.835	1.96	2.01	2.27	-1.68	34.54	4.76 ^(d)	
(10,10)	120	10.39	11.85	2.46	1.80	1.835	1.945	2.02	2.27	-0.45	18.39	5.05 ^(d)	
(15,15)	180	10.33	17.33	2.43	1.785	1.87	1.92	2.01	2.27	-0.14	12.25	5.36 ⁽ⁱ⁾	
(20,20)	240	10.33	22.84	2.41	1.78	1.875	1.91	2.01	2.28	-0.07	8.51	5.28 ^(d)	
(24,24)	288	10.33	27.24	2.41	1.78	1.875	1.895	2.01	2.28	-0.03	6.57	5.24 ^(d)	

^aDefinitions of values are the same as in Table 13.20
^bLength of nanotube unit cell
^cDiameters are given for the middle cylinders between the external and internal walls of NTs
^dDirect and indirect bandgaps are marked by superscript indices ^(d) and ⁽ⁱ⁾, respectively

both nanotube chiralities achieve maxima at diameter range 13–17 Å and after its further growth both gaps asymptotically approach that for the corresponding 2D slab. The twelve-layer SW TiO₂ NTs were found in [1118] to be energetically non-stable as single-walled nanotubes. One can predict that for these nanotubes the more preferable morphology has to be double-walled (DW) NTs of the same chirality consisting of a pair of six-layer nanotubes of different diameters and chirality indices.

13.5 LCAO Calculations on SrTiO₃ Nanotubes with Square Morphology

13.5.1 Symmetry of SrTiO₃ Nanotubes

Owing to their novel size-dependent properties , the ferroelectric nanoscale structures of the perovskites PbTiO₃, BaTiO₃, and SrTiO₃ (nanotubes, nanowires, nanorods) have attracted extensive synthetic attention [1156–1161]. Monoperiodic nanotube/nanowire ATiO₃ (A=Sr, Ba, Pb) systems offer fundamental scientific opportunities for investigating the influence of the size and dimensionality of materials with respect to their optical, magnetic, and electronic properties [1115, 1163–1165]. Such materials have a potential application as nanosized ferroelectrics

and memory elements. In particular, SrTiO₃ (STO) nanotubes have been synthesized using a low-temperature hydrochemical method [1115]. A titanium oxide (TiO₂) nanotube was utilized as a precursor material in order to generate the corresponding perovskite transition metal oxide nanotubes. Using transmission electron spectroscopy (TEM) methodology, it was revealed in [1115] that STO NTs have an outer diameter of 8–15 nm and an inner diameter from 4 to 7 nm. Powder X-ray diffraction patterns demonstrated the conversion of the precursor TiO₂ nanotube, composed of the crystalline phase of anatase, to crystalline STO nanotubes with cubic perovskite structure. The experimental NT unit cell parameter $a = 3.89 \text{ \AA}$ is close to $a = 3.90 \text{ \AA}$ of the bulk cubic STO.

First-principles density functional theory-based (DFT-based) methods complement the experimental developments both on the bulk cubic perovskites (see [1162] and references therein) and on anatase-based TiO₂ nanotubes [1116, 1118, 1123]. In the latter case, the formalism of line symmetry groups for one-periodic (1D) nanostructures with rotohelical symmetry was applied.

Recent DFT studies of the ferroelectric properties of PbTiO₃ [1165] and BaTiO₃ [1163] nanowires allowed the finding of the critical size for ferroelectricity via polarization along the nanowire axis. The first DFT calculations for perovskite nanotubes are made in [1125].

The full symmetry study of SrTiO₃ nanotubes with square morphology was given in [1119] for the first time.

In the case of SrTiO₃, the folding procedure is applied to the most stable (001) slab cut from the bulk crystal with the cubic space group $221(Pm\bar{3}m)$. The initial slab symmetry is described by the square plane lattice. The slab layer symmetry group depends on the number of layers included in the folding procedure. Figure 13.20 shows 2-, 3-, and 4-layer slabs cut from the bulk SrTiO₃ with one formula unit in the bulk unit cell.

For an even number of layers, the slab layer group is $P4mm$ (55); for an odd number of layers, this group becomes $P4/mmm$ (61). This follows from the scanning tables given in [1103] and connecting the space groups with the sectional layer groups. The latter are defined by 2D lattice Miller indices (hkl).

For the general rolling vector $\mathbf{R}(n_1, n_2)$, the symmetry of these tubes is given by the line group $\mathbf{L}^{(5)}$ (see Table 13.4), which is $q_p 22$ or $q_p 2$ for the even and odd q , respectively. Here q is the number of square lattice cells in the supercell and defines the main rotation axis order of the nanotube. Due to the relation (13.6c), SW nanotubes with square morphology are commensurate for any rolling vector $\mathbf{R}(n_1, n_2)$.

Let $n_1 = 5$ and $n_2 = 7$. In this case, $l_1/l_2 = -7/5$ and $q = 74$. The greatest common divisor n_1 and n_2 is $n = 1$. The rototranslational vector $\mathbf{H}(h_1, h_2)$ is defined by $h_1 = 2$ and $h_2 = 7$. As $r = h_1 l_2 - h_2 l_1 = 31$, NT $\mathbf{R}(5, 7)$ with square morphology has the rototranslational axis T_{74}^{31} .

Let now $n_1 = n$ and $n_2 = 0$. In this case $q = n$, $l_1 = 0$, $l_2 = 1$, $h_1 = 0$, $h_2 = 1$, and $r = 0$. Thus, for SW (n,0) STO NTs, the line symmetry groups are symmorphic, belong to the family $\mathbf{L}^{(11)}$, and are n/mmm or $\bar{2}n2m$ for even and odd n , respectively. For SW (n,n) STO NTs, $q = 2n$, $l_1 = -1$, $l_2 = 1$, $h_1 = 0$,

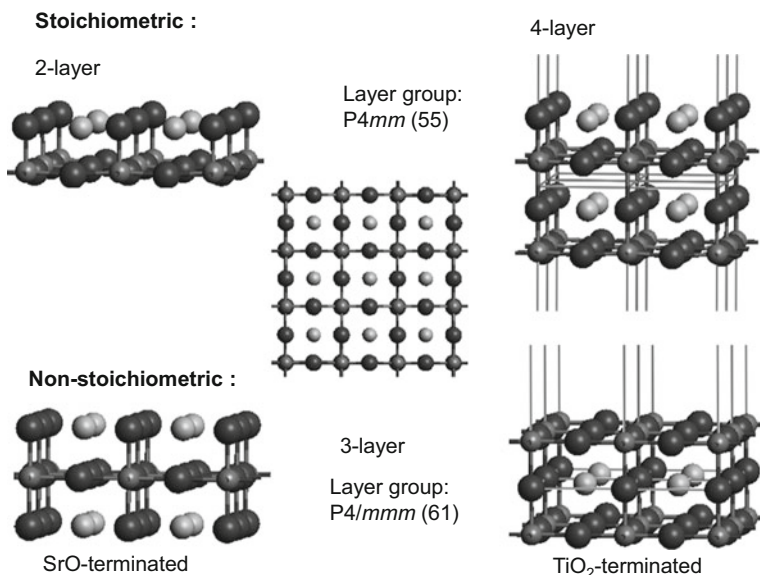


Fig. 13.20 STO slabs consisting of two or four alternating (001) SrO and TiO₂ atomic planes which have been used for nanotubes construction (lateral view). The top view along the [001] direction is shown in the middle. Legend: O—grey balls, Ti—small dark balls, Sr—light balls

$h_2 = 1$, and $r = 1$. Therefore, in this case, the line symmetry groups $(2n)_n/mcm$ belong to the family $L^{(13)}$. In both cases, the line groups do not depend on the number of layers N in the STO slab as for the layer groups 55 and 61, the folding procedure gives the line groups, which belong to the same family; see Table 13.5.

Table 13.22 presents the symmetry of SW STO nanotubes for the rolling vectors $(n, 0)$, family 11 and (n, n) , and family 13, respectively. This table gives also the NT diameter, defined by the length R of the rolling vector through the relation $D = R/\pi$. For STO nanotubes, the square lattice parameter $a = b$ is equal to the bulk STO cubic lattice parameter a so that $R = na$ for $(n, 0)$ and $R = na\sqrt{2}$ for (n, n) . The experimental value $a = 3.905 \text{ \AA}$ is used. The number of atoms (per monoperiodic unit cell) in two- and three-layer STO NTs is also given in Table 13.22. In the latter case the number of atoms is different in the tubes rolled up from SrO- and TiO₂-terminated layers.

It is seen from Table 13.22 that for the tubes studied experimentally (their diameters are 4–8 nm), computer modeling is very time consuming—these tubes consist of several hundred atoms in the monoperiodic unit cell. Fortunately, the higher NT diameter, the larger the order of the rotohelical axis. This symmetry is fully exploited in the CRYSTAL09 code for the first-principles LCAO calculations of nanotubes; see references [953, 1111].

The STO DW NTs $(n_1, n_1)@(n_2, n_2)$ and $(n_1, 0)@(n_2, 0)$ are commensurate; the minimal translation period of such DW NTs is the same as for the constituents.

Table 13.22 Symmetry of SrTiO₃ single-wall nanotubes with square morphology. LG 55- and LG 61-layer symmetry groups of stoichiometric and nonstoichiometric slabs, respectively

				N_A - number of atoms in SW NT		
				Two-layer, LG 55	Three-layer, SrO term. LG 61	Three-layer, TiO ₂ term. LG 61
SW NT	D , Å	Line group	Point group			
(a) Chirality $(n, 0)$						
(6,0)	7.46	$6/mmm$	D_{6h}	30	42	48
(8,0)	9.94	$8mmm$	D_{8h}	40	56	64
(12,0)	14.92	$12/mmm$	D_{12h}	60	84	96
(16,0)	19.89	$16mmm$	D_{16h}	80	112	128
(18,0)	22.37	$18/mmm$	D_{18h}	90	126	144
(20,0)	24.86	$20mm$	D_{20h}	100	140	160
(24,0)	29.83	$24/mmm$	D_{24h}	120	168	192
(32,0)	39.78	$32/mmm$	D_{32h}	160	224	256
(36,0)	44.75	$36/mmm$	D_{36h}	180	252	288
(40,0)	49.72	$40/mmm$	D_{40h}	200	280	320
(48,0)	59.66	$48/mmm$	D_{48h}	240	336	384
(b) Chirality (n, n)						
(6,6)	10.55	$12_6/mmm$	D_{12h}	60	84	96
(8,8)	14.06	$16_8/mmm$	D_{16h}	80	112	128
(12,12)	21.10	$24_{12}/mmm$	D_{24h}	120	168	192
(16,16)	28.13	$32_{16}/mmm$	D_{32h}	160	224	256
(18,18)	31.64	$36_{18}/mmm$	D_{36h}	180	252	288
(20,20)	35.16	$40_{20}/mmm$	D_{40h}	200	280	320
(24,24)	42.19	$48_{24}/mmm$	D_{48h}	240	336	384
(36,36)	63.29	$72_{36}/mmm$	D_{72h}	360	504	576

Table 13.23 presents the symmetry of STO DW NTs. The symmetry group of DW NT (*n*, 0)@*M*(*n*, 0) belongs to the same family 11 as its SW constituents. The symmetry of DW NT (*n*, *n*)@*M*(*n*, *n*) depends on the parity of *M*. For DW NTs with an odd *M*, the line symmetry groups are the same as for their SW constituents and belong to family 13. For an even *M*, the rotations about the screw axis of the order 2*n* are changed by the rotations around the pure rotation axis of the order *n* so that DW NT line symmetry groups belong to family 11. As is seen from Table 13.23, the symmetry of (*n*₁, *n*₁)@(*n*₂, *n*₂) and (*n*₁, 0)@(*n*₂, 0) STO nanotubes depends on the parity of the numbers *n*₁/*GCD*(*n*₁, *n*₂) and *n*₂/*GCD*(*n*₁, *n*₂): if both of these numbers are odd, DW NT belongs to family 13; in other cases DW NT belongs to family 11.

In Table 13.23, we also present the distance *d* between the outer wall of the inner tube and the inner wall of the outer tube in two-layer (layer group 55) and 3-layer (layer group 61) nanotubes. This distance is calculated for *a* = 3.905 Å (translation vector for DW NTs (*n*₁, 0)@(*n*₂, 0)) and *a* = 3.905√2 = 5.522 Å (translation vector for DW NTs (*n*₁, *n*₁)@(*n*₂, *n*₂)). This distance is different for 2-layer

Table 13.23 Symmetry of commensurate SrTiO₃ double-wall nanotubes with square morphology; d - distance between the outer wall of the inner tube and the inner wall of the outer tube

(a) Chiralities $(n, n)@M(n, n)$ and $(n, 0)@M(n, 0)$								
DW NT	M	Line group	Point group	$d, \text{\AA}$			N_A —number of atoms in DW NT	
				LG 55	LG 61	LG 55	LG 61, SrO term.	LG 61, TiO ₂ term.
(6,0)@(18,0)	3	6/ <i>mmm</i>	D_{6h}	5.50	3.55	120	168	192
(12,0)@(24,0)	2	12/ <i>mmm</i>	D_{12h}	5.50	3.55	180	252	288
(6,6)@(18,18)	3	12 ₆ / <i>mmm</i>	D_{12h}	8.59	6.64	240	336	384
(12,12)@(24,24)	2	12/ <i>mmm</i>	D_{12h}	8.59	6.64	360	504	576
(12,0)@(36,0)	3	12/ <i>mmm</i>	D_{12h}	12.96	11.01	240	336	384
(12,12)@(36,36)	3	24 ₁₂ / <i>mmm</i>	D_{24h}	19.14	17.19	480	672	768

(b) Chiralities $(n_1, n_1)@M(n_2, n_2)$ and $(n_1, 0)@M(n_2, 0)$								
DW NT	CGD (n_1, n_2)	Line group	Point group	$d, \text{\AA}$			N_A —number of atoms in DW NT	
				LG 55	LG 61	LG 55	LG 61, SrO term.	LG 61, TiO ₂ term.
(12,0)@(26,0)	2	2/ <i>mmm</i>	D_{2h}	6.75	4.80	190	266	304
(12,0)@(27,0)	3	3/ <i>mmm</i>	D_{3h}	7.37	5.42	195	273	312
(12,0)@(28,0)	4	4/ <i>mmm</i>	D_{4h}	7.99	6.04	200	280	320
(12,12)@(26,26)	2	2/ <i>mmm</i>	D_{2h}	10.35	8.40	380	532	608
(12,12)@(27,27)	3	3/ <i>mmm</i>	D_{3h}	11.23	9.28	390	546	624
(12,12)@(28,28)	4	8 ₄ / <i>mmm</i>	D_{8h}	12.11	10.16	400	560	640

and 3-layer nanotubes with the same chiralities of both SW constituents (see Table 13.23). However, the distance d is the same for SrO- and TiO₂-terminated 3-layer tubes with the same chiralities of both SW constituents. All these distances are given for the unrelaxed tubes rolled up from the 2- or 3-layer slabs. The relaxation of the tubes can change not only the intertube distances but also the symmetry of DW NTs.

13.5.2 LCAO Calculations of SrTiO₃ Nanotubes

Let us discuss the results of LCAO PBE0 calculations of STO nanotubes [1125]. The initial structures of the nanotubes were obtained by the rolling up of the stoichiometric SrTiO₃ slabs consisting of two or four alternating (001) SrO and TiO₂ atomic planes (Fig. 13.20). Two different NTs can be constructed for each chirality: (I) with a SrO outer shell (SrO terminated), and (II) with a TiO₂ outer shell (TiO₂ terminated). The inner shell has an alternate composition for the adopted even

number of planes in the slab. All calculations were made using the periodic PBE0 LCAO method via the CRYSTAL09 [953] computer code. The basis set for the Ti and O atoms was taken from [1118]. Small-core pseudopotentials [1166] and the corresponding basis set were used for the Sr atom. Diffuse exponents smaller than 0.1 a.u. were removed, and the exponents of other polarization functions were reoptimized for the periodic calculations. The method chosen provides a good quality of the calculated STO bulk properties. Thus, optimized lattice constant of the cubic STO (3.89 Å) is very close to the experimental value (3.90 Å).

The optimized lattice constant of the two-dimensional square lattice is slightly decreased compared to the bulk value and becomes 3.82 Å for a two-layer slab and 3.85 Å for a four-layer slab. The atomic positions on the boundary planes exhibit a noticeable relaxation, which in general resembles that on the surface of the thicker STO slabs [812, 814]. The slab thickness (difference in the z-coordinate of top and bottom oxygens) is 1.99 Å for a two-layer (001) slab and 5.90 Å for a four-layer (001) slab.

After the slab–NT rolling, the positions of all the atoms were optimized to obtain the most stable NT structure preserving only the rototranslational symmetry. Other symmetry constraints on NTs (second-order *U*-axis normal to the tube axis and reflection planes) were removed during the atomic relaxation. The one-dimensional Brillouin zone was sampled with 16 (for chiralities (*n*, 0)) or 12 (for chiralities (*n*, *n*)) *k*-points. The lattice parameters and atomic structure of the initial slabs were optimized before the folding to provide the estimation of the NT strain energy:

$$E_{\text{str}}(\text{NT}) = E_l(\text{NT})/l - E_m(\text{slab})/m \quad (13.14)$$

where $E_l(\text{NT})$ —total energy of the NT unit cell consisting of *l* bulk formula units and $E_m(\text{slab})$ —the total energy of the slab unit cell including *m* bulk formula units.

During the slab folding, the inner and outer atomic shells undergo a considerable stress due to the stretching or shrinking of the interatomic distances relative to those in the initial relaxed slab. The lesser the tube diameter, the greater the strain. The most critical is the repulsion between the nearest oxygen atoms in the inner shells, and as a rule the distance between them cannot be less than 2.7–2.6 Å. The atomic and cell relaxation can reduce the indicated strain, but only to some extent. The inner and outer shells are strained in the opposite directions, so reducing the tension in the former can increase the tension in the latter. For example, the expansion of the NT diameter leads to a reduction of the bond shrinking in the inner tube shell; however, this also leads to an increase in the bond stretching in the outer tube shell. As a result, for each NT chirality, there exist a minimum diameter, below which NT is very unstable and undergoes spontaneous destruction. Depending on the relation between the inner and outer strain and on the chemical bond pattern in the inner and outer shells, the initial diameter of the rolled NT (which is defined by the slab lattice parameters) can increase or decrease.

In Table 13.24, the calculated properties of two-layer STO NTs are given (See Fig. 13.21).

Table 13.24 Properties^a of SrTiO₃ two-layer nanotubes

Type I (SrO outer shell)						Type II (TiO ₂ outer shell)					
Chirality	<i>L</i> , Å	<i>d</i> , Å	<i>w</i> , Å	<i>E</i> _{str} , kJ/mol	<i>E</i> _{gap} , eV	Chirality	<i>L</i> , Å	<i>d</i> , Å	<i>w</i> , Å	<i>E</i> _{str} , kJ/mol	<i>E</i> _{gap} , eV
(8 0)	3.97	13.3	1.9	80.2	4.3	(8 0)	3.49	13.7	2.2	10.4	6.4
(12 0)	3.94	18.2	1.9	54.1	4.3	(12 0)	3.57	18.4	2.2	13.1	5.9
(16 0)	3.90	23.1	1.9	37.5	4.4	(16 0)	3.65	22.7	2.1	13.2	5.4
(20 0)	3.88	27.9	1.9	28.1	4.2	(20 0)	3.73	26.7	2.1	11.3	4.9
(24 0)	3.87	32.8	1.9	21.9	4.2	(24 0)	3.76	31.0	2.1	8.1	4.5
(32 0)	3.85	42.5	2.0	14.8	4.1	(32 0)	3.79	40.3	2.0	4.4	4.1
(6 6)	5.46	14.1	1.8	25.8	4.7	(6 6)	5.61	12.6	2.0	119.0	5.8
(8 8)	5.45	17.6	1.9	25.0	4.5	(8 8)	5.47	15.7	2.0	71.3	5.1
(12 12)	5.45	24.5	1.9	19.8	4.3	(12 12)	5.40	22.1	2.0	27.3	4.3
(16 16)	5.44	31.3	1.9	15.3	4.2	(16 16)	5.37	28.7	2.0	10.2	3.6
(20 20)	5.43	38.1	1.9	12.3	4.1	(20 20)	5.38	35.4	2.0	3.9	3.7
(24 24)	5.43	45.0	1.9	10.0	4.1	(24 24)	5.38	42.2	2.0	1.0	3.7

^a Period *L*, maximal diameter *d*, thickness *w*, strain energy *E*_{str}, and bandgap *E*_{gap} (in slab *E*_{gap} = 3.9 eV)

The external diameter *d* of an NT is estimated as the double distance from the NT axis to the most remote atom. Almost in all the NTs considered, the most remote atom is oxygen. The tube thickness *w* was estimated as the difference in the distances between the atoms that are the most distant from the tube axis and those that are the closest to it. During the atomic relaxation, the period *L* of type I NTs (SrO outer shell) is reduced, while the period of type II NTs (TiO₂ outer shell) is increased relative to the initial (slab) value. On the other hand, the thickness of the tube walls is slightly less for the former than for the latter.

As was expected, the strain energy falls down upon the increasing of the width of the NTs. Type II NTs have rather small values of the strain energy, especially for large (≥ 30 Å) diameters. The calculated bandgap is indirect for (*n*, 0) chirality and direct for (*n*, *n*) chirality. The bandgap of type I NTs is slightly greater than the bandgap of the two-layer slab, and it decreases slowly with *n*. The bandgap for narrow NTs of type II is considerably greater than that for the slab, but it decreases fast with *n* increasing. The covalent component of the chemical bonds in the outer SrO shell is weak, so the expansion does not break the narrow two-layer tubes of type I. On the other hand, such an expansion can destroy the essentially covalent Ti–O bonds in the outer shell of type II NTs. This really occurs upon the optimization of type II tube with chirality (6,6), which is found to be totally destroyed. Nanotubes of type II with chirality (*n*, 0), where *n* is less or equal to 20, also break down to weakly bonded one-dimensional chains of SrTiO₃ molecules. The distance between the interacting Ti and O atoms in the neighboring chains is about 2.4–2.6 Å. In spite of a disintegration at small *n*, the strain energy of the two-layer tubes (*n*, 0) with a TiO₂ outer shell is relatively low for all *n* values considered (see Table 13.24).

More interesting results should be expected for four-layer NTs because they provide more realistic models of NTs observed experimentally. Computer facilities

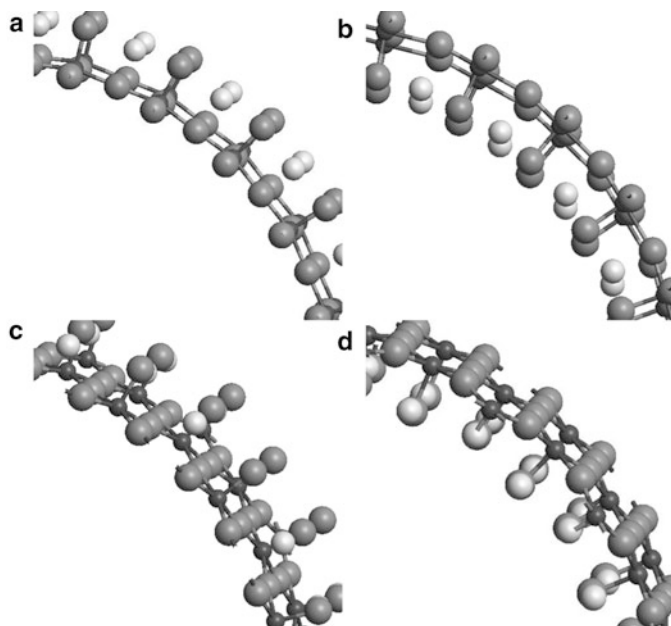


Fig. 13.21 Structure of SrTiO₃ NTs consisting of two atomic layers with different chiralities (view along the tube axis). Chirality (20,0): (a)—type I with SrO outer shell; (b)—type II with TiO₂ outer shell. Chirality (16,16): (c)—type I with SrO outer shell; (d)—type II with TiO₂ outer shell. See Fig. 13.20 for legend

allowed the calculation of four-layer NTs with chiralities up to (48,0) and (24,24, which comprise 480 atoms). The obtained results for four-layer NTs are given in Table 13.25.

The relatively stable four-layer NTs arise at greater diameters than the two-layer NTs because of a large curvature difference between the inner and the outer shells provoking a considerable stretching and shrinking of the external and internal NT surfaces. Also, the surface structure of the four-layer tubes changes considerably during atomic and cell relaxation. However, the period of the four-layer NTs is not changed noticeably upon the relaxation because of the relatively large tube thickness, except for the type II of $(n, 0)$ NTs where it is reduced by about 0.1–0.2 Å. This reduction may be connected with the surface reconstruction observed in this case (see below). The dependence of NT thickness on the chirality and surface type is rather complex, and possibly the additional computations are needed to analyze it in detail. During the relaxation at large n , the diameter of the type I NT $(n, 0)$ is slightly reduced, and its inner surface exhibits corrugation (see Fig. 13.22a).

At the same time, the diameter of the type II NT $(n, 0)$ increases, and the external NT surface undergoes a very prominent reconstruction which is accompanied by the breaking of some transverse (equatorial) Ti–O bonds and a formation of short

Table 13.25 Properties^a of SrTiO₃ four-layer nanotubes

Type I (SrO outer shell)						Type II (TiO ₂ outer shell)					
Chirality	<i>L</i> , Å	<i>d</i> , Å	<i>w</i> , Å	<i>E</i> _{str} , kJ/mol	<i>E</i> _{gap} , eV	Chirality	<i>L</i> , Å	<i>d</i> , Å	<i>w</i> , Å	<i>E</i> _{str} , kJ/mol	<i>E</i> _{gap} , eV
(18 0)	3.81	32.1	5.5	66.5	4.4	(18 0)	3.65	32.2	6.0	14.5	5.4
(24 0)	3.80	39.7	5.5	52.8	4.3	(24 0)	3.69	38.9	6.0	12.5	5.1
(32 0)	3.89	45.4	6.5	41.2	3.8	(32 0)	3.73	48.1	6.0	9.5	4.6
(48 0)	3.90	63.9	6.5	21.5	2.7	(48 0)	3.76	67.0	6.0	7.6	3.5
(12 12)	5.48	30.7	5.3	126.7	3.7	(12 12)	5.55	28.7	5.6	111.4	4.3
(16 16)	5.52	34.5	6.5	91.2	3.4	(16 16)	5.52	35.1	5.7	80.9	4.0
(24 24)	5.49	49.8	5.7	48.1	2.7	(24 24)	5.48	48.3	5.8	43.4	3.6

^a Period *L*, maximal diameter *d*, thickness *w*, strain energy *E*_{str}, and bandgap *E*_{gap} (in slab *E*_{gap} = 2.6 eV)

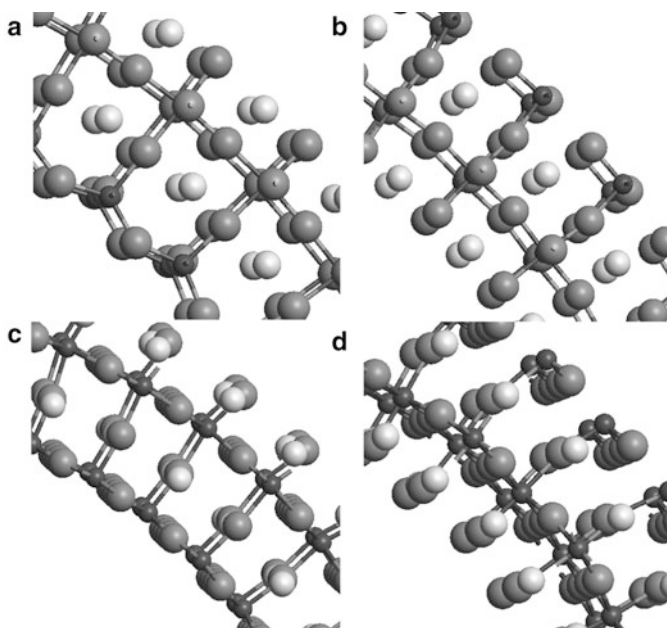


Fig. 13.22 Structure of SrTiO₃ NTs consisting of four atomic layers with different chiralities (view along the tube axis). Chirality (48,0): (a)—type I with SrO outer shell; (b)—type II with TiO₂ outer shell. Chirality (24,24): (c)—type I with SrO outer shell; (d)—type II with TiO₂ outer shell. See Fig. 13.20 for the legend

(1.75 Å) Ti–O (titanyl) bonds. Accordingly, the reflection planes passing through the tube axis disappear, and the symmetry is reduced to *C_{nh}*.

In (*n*, *n*) case, one observes the increasing of the NT diameter during the atomic relaxation of both surface types. For a type II NT (Fig. 13.22d), a considerable reconstruction of the external surface layer was again observed. Its optimized structure is composed of isolated TiO₂ fragments (which, however, are connected to

the underneath oxygen atoms by the normal Ti–O bond with the length of 1.81 Å). The lengths of the two Ti–O bonds in a TiO₂ fragment are equal to 1.77 Å. The NT symmetry is reduced to C_{2nh} .

As can be seen from Table 13.25, the nanotubes ($n, 0$) with the TiO₂ external surface are the most stable, and their stability depends on the tube diameter only slightly. It is interesting that the broken Ti–O bonds on the tube external surface does not influence this high stability. These tubes also have a remarkably high value of the bandgap, which is greater than the corresponding bulk and slab values. As in the case of two-layer NTs, the bandgap is indirect for ($n, 0$) chirality and direct for (n, n) chirality.

Basing on the results obtained, the following conclusions were made in [1125]. In most of cases, considered inner or outer TiO₂ shells of SrTiO₃ NTs undergo a considerable reconstruction due to the shrinkage or stretching of the interatomic distances in the initial cubic perovskite structure. The two types of surface reconstruction were found: (1) the breaking of Ti–O bonds accompanied by creating of Ti–O titanyl groups in the outer surface and (2) the inner surface folding due to Ti–O–Ti bending. Based on the strain energy calculations, the largest stability was found for ($n, 0$) NTs with a TiO₂ outer shell.

The discussion of nanotube modeling concludes Part II (Applications) of this book. We tried to demonstrate, via numerous examples, the efficiency of modern quantum-chemical approaches to calculate the properties of crystalline solids—bulk and defective crystals, surfaces and adsorption, and nanotubes.

The list of computer programs used in LCAO (both *ab initio* and semiempirical) calculations of periodic systems is given in Appendix C.

Appendix A

Matrices of the Symmetrical Supercell Transformations of 14 Three-Dimensional Bravais Lattices

A.1. The triclinic crystal system

(i) $l(\mathbf{P}, \mathbf{P})$ is an arbitrary integer matrix.

A.2. The monoclinic crystal system

$$(i) \quad l(\mathbf{P}, \mathbf{P}) = \begin{pmatrix} n_1 & n_5 & 0 \\ n_4 & n_2 & 0 \\ 0 & 0 & n_3 \end{pmatrix}, \quad L = (n_1 n_2 - n_4 n_5) n_3. \quad (\text{A.1})$$

$$(ii) \quad l(\mathbf{A}, \mathbf{P}) = \begin{pmatrix} n_1 & n_5 & 0 \\ n_4 & n_2 & -n_3 \\ n_4 & n_2 & n_3 \end{pmatrix}, \quad L = 2(n_1 n_2 - n_4 n_5) n_3.$$

$$(iii) \quad l(\mathbf{P}, \mathbf{A}) = \begin{pmatrix} n_1 & n_4 & n_4 \\ n_5 & n_2 & n_2 \\ 0 & -n_3 & n_3 \end{pmatrix}, \quad L = 2(n_1 n_2 - n_4 n_5) n_3.$$

$$(iv) \quad l(\mathbf{A}, \mathbf{A}) = \begin{pmatrix} n_1 & n_5 & n_5 \\ n_4 & n_2 + n_3 & n_2 - n_3 \\ n_4 & n_2 - n_3 & n_2 + n_3 \end{pmatrix}, \quad L = 4(n_1 n_2 - n_4 n_5) n_3.$$

A.3. The hexagonal crystal system

$$(i) \quad l^{(1)}(\mathbf{P}, \mathbf{P}) = \begin{pmatrix} n_1 & 0 & 0 \\ 0 & n_1 & 0 \\ 0 & 0 & n_2 \end{pmatrix}, \quad L = n_1^2 n_2. \quad (\text{A.2})$$

$$(ii) \quad l^{(2)}(\mathbf{P}, \mathbf{P}) = \begin{pmatrix} n_1 & -n_1 & 0 \\ n_1 & 2n_1 & 0 \\ 0 & 0 & n_2 \end{pmatrix}, \quad L = 3n_1^2 n_2.$$

A.4. The rhombohedral crystal system

$$(i) \quad l(R,R) = \begin{pmatrix} n_1 + n_2 & n_2 & n_2 \\ n_2 & n_1 + n_2 & n_2 \\ n_2 & n_2 & n_1 + n_2 \end{pmatrix}, \quad L = n_1^2(n_1 + 3n_2).$$

A.5. The orthorhombic crystal system

(i) $l(P,P)$ coincides with (A.1).

$$(ii) \quad l(C,P) = \begin{pmatrix} n_1 & -n_2 & 0 \\ n_1 & n_2 & 0 \\ 0 & 0 & n_3 \end{pmatrix}, \quad L = 2n_1n_2n_3.$$

$$(iii) \quad l(F,P) = \begin{pmatrix} 0 & n_2 & n_3 \\ n_1 & 0 & n_3 \\ n_1 & n_2 & 0 \end{pmatrix}, \quad L = 2n_1n_2n_3.$$

$$(iv) \quad l(I,P) = \begin{pmatrix} -n_1 & n_2 & n_3 \\ n_1 & -n_2 & n_3 \\ n_1 & n_2 & -n_3 \end{pmatrix}, \quad L = 4n_1n_2n_3.$$

$$(v) \quad l(P,C) = \begin{pmatrix} n_1 & n_1 & 0 \\ -n_2 & n_2 & 0 \\ 0 & 0 & n_3 \end{pmatrix}, \quad L = 2n_1n_2n_3.$$

$$(vi) \quad l(C,C) = \begin{pmatrix} n_1 & n_2 & 0 \\ n_2 & n_1 & 0 \\ 0 & 0 & n_3 \end{pmatrix}, \quad L = (n_1^2 - n_2^2)n_3.$$

$$(vii) \quad l(A,C) = \begin{pmatrix} n_1 & n_1 & 0 \\ -n_2 & n_2 & -n_3 \\ -n_2 & n_2 & n_3 \end{pmatrix}, \quad L = 4n_1n_2n_3.$$

$$(viii) \quad l(F,C) = \begin{pmatrix} -n_2 & n_2 & n_3 \\ n_1 & n_1 & n_3 \\ n_1 - n_2 & n_1 + n_2 & 0 \end{pmatrix}, \quad L = 4n_1n_2n_3.$$

$$(ix) \quad l(I,C) = \begin{pmatrix} -n_1 & -n_2 & n_3 \\ n_1 & n_2 & n_3 \\ n_2 & n_1 & -n_3 \end{pmatrix}, \quad L = 2(n_1^2 - n_2^2)n_3.$$

$$(x) \quad l(P,F) = \begin{pmatrix} -n_1 & n_1 & n_1 \\ n_2 & -n_2 & n_2 \\ n_3 & n_3 & -n_3 \end{pmatrix}, \quad L = 4n_1n_2n_3.$$

$$(xi) \quad l(C,F) = \begin{pmatrix} -n_1 & n_1 & n_2 \\ -n_2 & n_2 & n_1 \\ n_3 & n_3 & -n_3 \end{pmatrix}, \quad L = 2(n_1^2 - n_2^2)n_3.$$

$$(xii) \quad l(F,F) = \frac{1}{2} \begin{pmatrix} n_2 + n_3 & -n_2 + n_3 & n_2 - n_3 \\ -n_1 + n_3 & n_1 + n_3 & n_1 - n_3 \\ -n_1 + n_2 & n_1 - n_2 & n_1 + n_2 \end{pmatrix}, \quad \begin{array}{l} L = n_1n_2n_3; \\ n_1, n_2, n_3 \text{ are of} \\ \text{the same parity.} \end{array}$$

$$\begin{aligned}
\text{(xiii)} \quad l(\mathbf{I}, \mathbf{F}) &= \begin{pmatrix} n_1 + n_2 + n_3 & -n_3 & -n_2 \\ -n_3 & n_1 + n_2 + n_3 & -n_1 \\ -n_2 & -n_1 & n_1 + n_2 + n_3 \end{pmatrix}, \\
L &= 2[(n_1 + n_2 + n_3)(n_1 n_2 + n_2 n_3 + n_3 n_1) - n_1 n_2 n_3]. \\
\text{(xiv)} \quad l(\mathbf{P}, \mathbf{I}) &= \begin{pmatrix} 0 & n_1 & n_1 \\ n_2 & 0 & n_2 \\ n_3 & n_3 & 0 \end{pmatrix}, \quad L = 2n_1 n_2 n_3. \\
\text{(xv)} \quad l(\mathbf{C}, \mathbf{I}) &= \begin{pmatrix} -n_2 & n_1 & n_1 - n_2 \\ n_2 & n_1 & n_1 + n_2 \\ n_3 & n_3 & 0 \end{pmatrix}, \quad L = 4n_1 n_2 n_3. \\
\text{(xvi)} \quad l(\mathbf{F}, \mathbf{I}) &= \begin{pmatrix} n_2 + n_3 & n_3 & n_2 \\ n_3 & n_1 + n_3 & n_1 \\ n_2 & n_1 & n_1 + n_2 \end{pmatrix}, \quad L = 4n_1 n_2 n_3. \\
\text{(xvii)} \quad l(\mathbf{I}, \mathbf{I}) &= \frac{1}{2} \begin{pmatrix} n_2 + n_3 & -n_1 + n_3 & -n_1 + n_2 \\ -n_2 + n_3 & n_1 + n_3 & n_1 - n_2 \\ n_2 - n_3 & n_1 - n_3 & n_1 + n_2 \end{pmatrix}, \quad \begin{array}{l} L = n_1 n_2 n_3; \\ n_1, n_2, n_3 \text{ are of} \\ \text{the same parity.} \end{array}
\end{aligned}$$

A.6. The tetragonal crystal system

$$\begin{aligned}
\text{(i)} \quad l^{(1)}(\mathbf{P}, \mathbf{P}) &\text{ coincides with (A.2).} \\
\text{(ii)} \quad l^{(2)}(\mathbf{P}, \mathbf{P}) &= \begin{pmatrix} n_1 & -n_1 & 0 \\ n_1 & n_1 & 0 \\ 0 & 0 & n_2 \end{pmatrix}, \quad L = 2n_1^2 n_2. \\
\text{(iii)} \quad l^{(1)}(\mathbf{I}, \mathbf{P}) &= \begin{pmatrix} 0 & n_1 & n_2 \\ n_1 & n_2 & \\ n_1 & n_1 & 0 \end{pmatrix}, \quad L = 2n_1^2 n_2. \\
\text{(iv)} \quad l^{(2)}(\mathbf{I}, \mathbf{P}) &= \begin{pmatrix} -n_1 & n_1 & n_2 \\ n_1 & -n_1 & n_2 \\ n_1 & n_1 - 1 & -n_2 \end{pmatrix}, \quad L = 4n_1^2 n_2. \\
\text{(v)} \quad l^{(1)}(\mathbf{P}, \mathbf{I}) &= \begin{pmatrix} 0 & n_1 & n_1 \\ n_1 & 0 & n_1 \\ n_2 & n_2 & 0 \end{pmatrix}, \quad L = 2n_1^2 n_2. \\
\text{(vi)} \quad l^{(2)}(\mathbf{P}, \mathbf{I}) &= \begin{pmatrix} -n_1 & n_1 & 0 \\ n_1 & n_1 & 2n_1 \\ n_2 & n_2 & 0 \end{pmatrix}, \quad L = 4n_1^2 n_2. \\
\text{(vii)} \quad l^{(1)}(\mathbf{I}, \mathbf{I}) &= \begin{pmatrix} n_1 + n_2 & n_2 & n_1 \\ n_2 & n_1 + n_2 & n_1 \\ n_1 & n_1 & 2n_1 \end{pmatrix}, \quad L = 4n_1^2 n_2. \\
\text{(viii)} \quad l^{(2)}(\mathbf{I}, \mathbf{I}) &= \frac{1}{2} \begin{pmatrix} n_1 + n_2 & -n_1 + n_2 & 0 \\ -n_1 + n_2 & n_1 + n_2 & 0 \\ n_1 - n_2 & n_1 - n_2 & 2n_1 \end{pmatrix}, \quad \begin{array}{l} L = n_1^2 n_2; \\ n_1, n_2 \text{ are of} \\ \text{the same parity.} \end{array}
\end{aligned}$$

A.7. The cubic crystal system

$$(i) \quad l(P,P)=l(F,F)=l(I,I)=\begin{pmatrix} n & 0 & 0 \\ 0 & n & 0 \\ 0 & 0 & n \end{pmatrix}, \quad L = n^3.$$

$$(ii) \quad l(F,P)=l(P,I)=\begin{pmatrix} 0 & n & n \\ n & 0 & n \\ n & n & 0 \end{pmatrix}, \quad L = 2n^3.$$

$$(iii) \quad l(I,P)=l(P,F)=\begin{pmatrix} -n & n & n \\ n & -n & n \\ n & n & -n \end{pmatrix}, \quad L = 4n^3.$$

$$(iv) \quad l(I,F)=\begin{pmatrix} 3n & -n & -n \\ -n & 3n & -n \\ -n & -n & 3n \end{pmatrix}, \quad L = 16n^3.$$

$$(v) \quad l(F,I)=\begin{pmatrix} 2n & n & n \\ n & 2n & n \\ n & n & 2n \end{pmatrix}, \quad L = 4n^3.$$

Appendix B

Reciprocal Matrices of the Symmetric Supercell Transformations of the Three Cubic Bravais Lattices

$$Q_1 = \begin{pmatrix} 1 & 0 & 0 \\ 0 & 1 & 0 \\ 0 & 0 & 1 \end{pmatrix} \quad Q_2 = \begin{pmatrix} -1 & 1 & 1 \\ 1 & -1 & 1 \\ 1 & 1 & -1 \end{pmatrix} \quad Q_3 = \begin{pmatrix} 0 & 1 & 1 \\ 1 & 0 & 1 \\ 1 & 1 & 0 \end{pmatrix}$$
$$Q_4 = \begin{pmatrix} 2 & 1 & 1 \\ 1 & 2 & 1 \\ 1 & 1 & 2 \end{pmatrix} \quad Q_5 = \begin{pmatrix} 3 & -1 & -1 \\ -1 & 3 & -1 \\ -1 & -1 & 3 \end{pmatrix}$$

Appendix C

Computer Programs for Periodic Calculations in Basis of Localized Orbitals

The information about computer programs applied in molecular quantum chemistry and materials science can be found on different Internet sites (<http://www.supercomputing.it/software.php?cat=11>, <http://www.msg.ku.edu/~msg/MGM/links/comp.html>, <http://www.redbrick.dcu.ie/~noel/linux4chemistry>). In particular, on site <http://www.supercomputing.it/software.php?cat=11> on-line links are given to the appropriate information. The majority of the existing computer codes for calculations of periodic systems can be divided into two main groups: LO codes using a basis set of localized orbitals (LO) and PW(APW) codes using plane waves (PW) or augmented plane waves (APW) as a basis set. The only exclusion is the hybrid Gaussian LO and PW (GPW) DFT code QIUCKSTEP/CP2K [839]. The sites mentioned include references to both LO and PW codes. The information about periodic codes using LO or PW bases can also be found in [552, 840]. Here, we restrict ourselves only to brief information about computer codes for periodic LO calculations (see Table C.1). The indication of the corresponding homepage and references on the publications is given in the last two columns of Table C.1. Both *ab initio* (HF, DFT (LDA, GGA), hybrid HF-DFT, time-dependent DFT (TDFT)) and semiempirical (SE) codes are included in the list. The codes listed allow all-electron (AE) calculations (also termed full potential FP) or valence-only ones with the use of pseudopotential (PP) for core electrons or both. For the localized basis, we use the acronyms GTO (Gaussian-type orbitals), STO (Slater-type orbitals), and NTO (numerical-type orbitals). In particular, *f*-GTO and *f*-polarization-GTO mean the possibility to make full GTO calculations for *f*-elements or the simple extension of Gaussian basis sets to include *f*-polarization basis functions, respectively. In the remaining cases, only *s*, *p*, and *d* orbitals can be used in the basis set. The geometry optimization can be made over the atomic coordinates only (GO) or including both the lattice parameters optimizations (full GO). Some codes allow linear scaling ($O(N)$) with the basis-set size and molecular-dynamics (MD) calculations. The semiempirical codes can allow the band-structure calculations for nonzero wavevectors (BAND), or the cyclic-cluster model (CCM) without the BZ summation can be used.

The CRYSTAL suite remains the mostly advanced and developing LCAO periodic program, compared to other codes listed in Table C.1. We refer the reader to the calculations of metal-organic frameworks (MOF),[852] as a case study showing that the CRYSTAL program allows reliable *ab initio* prediction of materials properties of complex systems to be made. Note that from January 1, 2007, CRYSTAL03 will not be supported any more.

The reader can also find useful such codes as XCrysDen (<http://www.ccr.jussieu.fr/ccr/Documentation/Calcul/XCRYSDEN/Documentation.html>), GULP (<http://www.ivec.org/GULP/>), and BAND-GUI (<http://www.scm.com/Doc/Doc2006.01>).

XCrysDen program can be used as a graphical user interface (GUI) for the CRYSTAL95/98/03/06 programs. The advantage of the GUI is its rendering possibility, which yields graphical feedback to the user. Every manipulation of the structure is visualized immediately, and to enhance the usefulness of XCrysDen even further, an UNDO/REDO option is available, which makes every false move recoverable. Several graphical procedures make the manipulation of the atomic structures easier, while other graphical functions are suitable for checking the geometry of the structure. This program uses the ease of a GUI and the flexibility of manual editing and allows the user to view and edit the input scripts for the CRYSTAL programs on request. Immediately after the manual editing is completed, the program visualizes the result. We refer the reader for details to the program description [853].

GULP is a program for performing a variety of types of simulation on materials using boundary conditions of 0D (molecules and clusters), 1D (polymers), 2D (surfaces, slabs, and grain boundaries), or 3D (periodic solids). The focus of the code is on analytical solutions, through the use of lattice dynamics, where possible, rather than on molecular dynamics. A variety of force fields can be used within GULP spanning the shell model for ionic materials, molecular mechanics for organic systems, and embedded-atom model for metals. Analytic derivatives are included up to at least second order for most force fields and to third order for many.

ADF2006.01 is the first ADF release, containing a graphical user interface for the BAND program. BAND input also enables inexperienced ADF-BAND users to easily create BAND jobs. You can use BAND input to define your periodic structure (geometry) and to set details of your BAND job using an easy-to-use graphical user interface. BAND input will generate the complete job script for you. This script takes care of running BAND. You can also use BAND input to run these script files on your local machine in the background.

Table C.1 List of periodic computer programs using localized orbitals basis

No	Program	Description	Web site	Refs
1	CRYSTAL03	HF;DFT (LDA,GGA); Hybrid HF-DFT; AE; PP; GTO; GO	www.crystal.unito.it www.cse.clrc.ac.uk/cmng	[552], [840–843]
2	CRYSTAL06	+ f -polarization-GTO, full GO, vibrational frequencies	www.crystal.unito.it/ home.html	
3	CRYSTAL09	+ static polarizability and dielectric tensor, new GGA functionals, helical symmetry for polymers, phonon dispersion, transition state search, automatic generation of nanotubes	www.crystal.unito.it/ home.html	
4	CRYSCOR	+ MP2 correlation	www.crystal.unito.it	[191]
5	GAUSSIAN03	HF;DFT (LDA, GGA); PHF; hybrid HF-DFT; AE; PP; f -GTO; GO; O(N)	www.gaussian.com	[366]
6	GAUSSIAN09	+ Model reactions of very large systems with ONIOM, study of excited states, enhanced solvent effects capabilities, additional spectra prediction	www.gaussian.com	
7	ADF2006 (BAND)	DFT (LDA, GGA); hybrid HF-DFT; TD-DFT; AE; STO;	/www.scm.com/Doc/ Doc2006.01	[844]
8	SIESTA	DFT (LDA, GGA);PP; NTO; GO; MD ; O(N)	www.uam.es/ departamentos/ ciencias/ fismateriac/siesta	[387]
9	AIMPRO	DFT(LDA,GGA); PP; LGTO	http://newton/ex/ ac.uk/research	[539]
10	SEQUEST	DFT (LDA, GGA);PP; GTO;O(N); GO	http://dft.sandia. gov/Quest	[845]
11	DMOL3	DFT (LDA, GGA);AE; NTO; GO	http://people.web.psi.ch/ delley/dmol3.html	[846]
12	FPLO	DFT (LSDA,LSDA+U); AE; LO	www.fplo.de	[847]

(continued)

Table C.1 (continued)

No	Program	Description	Web site	Refs
13	PLATO	DFT (LDA); NTO; GO	www-staff.lboro.ac.uk / masdk/plato.html	[848]
14	QUICKSTEP/ CP2K	DFT(LDA, GGA); PP; GTO/PW	http://cp2k.berlios.de	[839]
15	CNDO 4.0	SE, BAND, GE	www.wgc.chem.pu.ru / valera/cndo/ manual.html	[849]
16	MOPAC2002	SE, BAND, GE	www.cachesoftware. com/mopac	[302, 850]
17	MSINDO	SE, CCM, STO, GO, MD	www.theochem. uni-hannover.de/ Bredow/MSINDO	[246]
18	SOLID2000	SE, CCM, QR-INDO, STO, GO	www.stech.sk/stech	[297]
19	SYM-SYM	SE, CCM, INDO ,GO	soft/htm www.cmmmp.ucl.ac.uk / lev/recearc4/ node8.html	[851]

References

1. R. Dronskowski, *Computational Chemistry of Solid State Materials. A Guide for Materials Scientists, Chemists, Physicists and Others* (Wiley-VCH, Weinheim, 2005)
2. C.M. Quinn, *An Introduction to Quantum Chemistry of Solids* (Clarendon Press, Oxford, 1973)
3. A.A. Levin, *Solid State Quantum Chemistry* (McGraw-Hill, New York, 1977)
4. *Ab-initio Calculations of the Properties of Crystalline Materials*, ed. by C. Pisani. Lecture Notes in Chemistry, vol. 67 (Springer, Berlin, 1996)
5. P. Fulde, *Electron Correlations in Molecules and Solids*, 3rd edn. Springer Series in Solid State Sciences, vol. 100 (Springer, Berlin, 1995)
6. W. Harrison, *Electronic Structure and Properties of Solids: Physics of the Chemical Bond*, 2nd edn. (Dover, New York, 1989)
7. R. Hoffmann, *Solids and Surfaces: A Chemist View on Bonding in Extended Structures* (Wiley-VCH, Weinheim 1988)
8. M. Springborg, *Methods of Electronic Structure Calculations* (Wiley, Chichester 2000)
9. E. Kahiras, *Atomic and Electronic Structure of Solids* (Cambridge University Press, Cambridge, 2003)
10. R. Martin, *Electronic Structure. Basic Theory and Practical Methods* (Cambridge University Press, Cambridge, 2004)
11. L. Kantorovich, *Quantum Theory of the Solid State* (Kluwer Academic, Dordrecht, 2004)
12. K. Ohno, R. Esfarjani, Y. Kawazoe, *Computational Materials Science*. Springer Series in Solid State Sciences, vol. 129 (Springer, Berlin, 1999)
13. R.A. Evarestov, V.P. Smirnov, *Site Symmetry in Crystals: Theory and Applications*, 2nd edn. Springer Series in Solid State Sciences, vol. 108 (Springer, Berlin, 1997)
14. R.L. Flurry, *Symmetry Groups. Theory and Chemical Applications* (Prentice-Hall, Englewood Cliffs, 1980)
15. P.W.M. Jacobs, *Group Theory with Applications in Chemical Physics* (Cambridge University Press, New York, 2005)
16. Bilbao Crystallographic Server. The crystallographic site at the Condensed Matter; Physics Dept. of the University of the Basque Country. <http://www.cryst.ehu.es/>
17. A.P. Cracknell, B.L. Davies, S.C. Miller, W.F. Love, *Kronecker Product Tables*, vol. 1. General Introduction and Tables of Irreducible Representations of Space Groups (IFI/Plenum, New York, 1979)
18. M.I. Petrashen, E.D. Trifonov, *Applications of Group Theory in Quantum Mechanics* (MIT, Cambridge, 1969)
19. in *International Tables for Crystallography*, ed. by T. Hahn, A Space-group symmetry (Reidel, Dordrecht, 1983, Fifth Edition 2002, Corrected Reprint 2005)

20. Inorganic Crystal Structure Database (ICSD), <http://www.fiz-informationsdienste.de/en/DB/icsd/>
21. V.R. Saunders, R. Dovesi, C. Roetti, R. Orlando, C.M. Zicovich-Wilson, N.M. Harrison, *CRYSTAL-2003 Users Manual* (University of Torino, Torino, 2003). <http://www.crystal.unito.it>
22. Richard J.D. Tilley, *Crystals and Crystal Structures* (Wiley, New York, 2006)
23. A. Munoz, J.A. Alonso, M.J. Martinez-Lope, M.T. Casais, J.L. Martinez, M.T. Fernandez-Diaz, *Phys. Rev. B* **62**, 6498 (2000)
24. J.Z.H. Zhang, *Theory and Application of Quantum Molecular Dynamics* (World Scientific, Singapore, 1999)
25. G.L. Bir, G.E. Pikus, *Symmetry and Strain-induced Effects in Semiconductors* (Wiley, New York, 1972)
26. C. Zicovich-Wilson, R. Dovesi, *Int. J. Quant. Chem.* **67**, 299 (1998)
27. C. Zicovich-Wilson, R. Dovesi, *Int. J. Quant. Chem.* **67**, 311 (1998)
28. C.J. Bradley, A.P. Cracknell, *The Mathematical Theory of Symmetry in Solids* (Clarendon, Oxford, 1972)
29. O.V. Kovalev, in *Representations of the Crystallographic Space Groups: Irreducible Representations, Induced Representations and Corepresentations*, 2nd edn., ed. by H.T. Stokes, D.M. Hatch (Gordon and Breach, Philadelphia, 1993)
30. I. Shur, *J. F. Math.* **139**, 155 (1911)
31. G.Ya. Lyubarskii, *The Application of Group Theory in Physics* (Pergamon, Oxford, 1960)
32. C.Herring, *J. Franklin Inst.* **233**, 525 (1942)
33. M.W. Schmidt, K.K. Baldrige, J.A. Boatz, S.T. Elbert, M.S. Gordon, J.H. Jensen, S. Koseki, N. Matsunaga, K.A. Nguyen, S. Su, T.L. Windus, M. Dupuis, J.A.J. Montgomery Jr., *J. Comput. Chem.* **14**, 1347 (1993)
34. C. Edmiston, K. Ruedenberg, *Rev. Mod. Phys.* **35**, 457 (1963)
35. J. Pipek, P.G. Mezey, *J. Chem. Phys.* **90**, 4916 (1989)
36. S.F. Boys, *Rev. Mod. Phys.* **32**, 296 (1960)
37. J. Zak, *Phys. Rev. B* **23**, 2824 (1981)
38. H. Bacry, L. Michel, J. Zak, *Lect. Notes Phys.* **313**, 291 (Springer, Berlin, Heidelberg, 1988)
39. M. Schütz, G. Hetzer, H.-J. Werner, *J. Chem. Phys.* **111**, 5691 (1999)
40. V.P. Smirnov, D.E. Usvyat, *Phys. Rev. B* **64**, 245108 (2001)
41. G. Wannier, *Phys. Rev.* **52**, 191 (1937)
42. W. Kohn, *Phys. Rev.* **115**, 809 (1959)
43. J. Des Cloizeaux, *Phys. Rev.* **135**, A698 (1964)
44. N. Marzari, D. Vanderbilt, *Phys. Rev. B* **56**, 12847 (1997)
45. V.P. Smirnov, R.A. Evarestov, D.E. Usvyat, *Int. J. Quant. Chem.* **88**, 642 (2002)
46. B. Sporkmann, H. Bross, *Phys. Rev. B* **49**, 10869 (1994)
47. A. Shukla, M. Dolg, P. Fulde, H. Stoll, *Phys. Rev. B* **60**, 5211 (1999)
48. S. Goedecker, *Rev. Mod. Phys.* **71**, 1085 (1999)
49. I. Souza, R.M. Martin, N. Marzari, X. Zhao, D. Vanderbilt, *Phys. Rev. B* **62**, 15505 (2000)
50. P.Y. Yu, M. Cardona, *Fundamentals of Semiconductors. Physics and Materials Properties*, 3rd rev. and enlarged edn. (Springer, Berlin, 2005)
51. C.M. Zicovich-Wilson, R. Dovesi, V.R. Saunders, *J. Chem. Phys.* **115**, 9708 (2001)
52. I. Mayer, G. Rathen, S. Suhai, *Chem. Phys. Lett.* **293**, 81 (1998)
53. R.A. Evarestov, V.P. Smirnov, *Phys. Stat. Sol. (b)* **180**, 411 (1993)
54. J. Des Cloizeaux, *Phys. Rev.* **129**, 554 (1963)
55. W. Kohn, *Phys. Rev. B* **7**, 4388 (1973)
56. J.C. Slater, G.F. Koster, *Phys. Rev.* **94**, 1498 (1954)
57. V.P. Smirnov, D.E. Usvyat, *Phys. Rev. B* **59**, 9695 (1999)
58. N. Marzari, D. Vanderbilt, in *First-Principles Calculations for Ferroelectrics*, ed. by R.E. Cohen. AIP Conf. Proc. No 436 (AIP, Woodbury, 1998), p. 146
59. I. Souza, N. Marzari, D. Vanderbilt, *Phys. Rev. B* **65**, 035109 (2001)

60. C.M. Zicovich-Wilson, A. Bert, C. Roetti, R. Dovesi, V.R. Saunders, *J. Chem. Phys.* **116**, 1120 (2002)
61. A. Bert, M. Llunell, R. Dovesi, C.M. Zicovich-Wilson, *Phys. Chem. Chem. Phys.* **5**, 5319 (2003)
62. E. Clementi, C. Roetti, Roothaan–Hartree–Fock Atomic Functions. *Atomic Data Nuclear Data Tables* **14**, 177 (1974)
63. C.C.J. Roothaan, *Rev. Mod. Phys.* **23**, 69 (1951)
64. C.C.J. Roothaan, *Rev. Mod. Phys.* **32**, 179 (1960)
65. J.A. Pople, R.K. Nesbet, *J. Chem. Phys.* **22**, 571 (1954)
66. E. Apra, *Lect. Notes Chem.* **67**, 101 (1996)
67. R.A. Evarestov, I.I. Tupitsyn, *Phys. Solid State* **44**, 1656 (2002)
68. P.P. Ewald, *Ann. Phys.* **64**, 253 (1921)
69. A.B. Kunz, *Phys. Rev. B* **6**, 606 (1972)
70. J.J. Ladik, *Phys. Rep.* **313**, 171 (1999)
71. J.-M. Andre, L. Gouverneur, G. Leroy, *Int. J. Quant. Chem.* **1**, 427, 451 (1967)
72. C. Pisani, R. Dovesi, *Int. J. Quant. Chem.* **17**, 501, 517 (1980)
73. R. Dovesi, C. Pisani, C. Roetti, P. Dellarole, *Phys. Rev. B* **24**, 4170 (1981)
74. R. Dovesi, M. Causa, G. Angonoa, *Phys. Rev. B* **24**, 4177 (1981)
75. M. Causa, *Lect. Note Chem.* **67**, 91 (1996)
76. C. Pisani, U. Birkenheuer, *Comp. Phys. Commun.* **96**, 221 (1996)
77. K.N. Kudin, G.E. Scuseria, *Phys. Rev. B* **61**, 16440 (2000)
78. R. Improta, K.N. Kudin, G.E. Scuseria, V. Barone, *J. Am. Chem. Soc.* **124**, 113 (2002)
79. N.W. Ashcroft, N.D. Mermin, *Solid State Physics* (Cole, London, 1976)
80. M.F. Guest, V.R. Saunders, *Mol. Phys.* **28**, 819 (1974)
81. R.A. Evarestov, V.P. Smirnov, *J. Phys. Condens. Matter* **9**, 3023 (1997)
82. R.A. Evarestov, V.P. Smirnov, *Phys. Stat. Sol. (b)* **119**, 9 (1983)
83. D.J. Chadi, M.L. Cohen, *Phys. Rev. B* **8**, 5747 (1973)
84. J. Moreno, J.M. Soler, *Phys. Rev. B* **46**, 13891 (1992)
85. H.J. Monkhorst, J.D. Pack, *Phys. Rev. B* **13**, 5188 (1976)
86. R.A. Evarestov, V.P. Smirnov, *Phys. Rev. B* **70**, 233101 (2004)
87. A. Baldereschi, *Phys. Rev. B* **7**, 5212 (1973)
88. D. Vanderbilt, *Phys. Rev. B* **41**, 7892 (1990)
89. M. Causa, R. Dovesi, C. Roetti, *Phys. Rev. B* **43**, 11937 (1991)
90. R.A. Evarestov, V.A. Lovchikov, I.I. Tupitsin, *Phys. Stat. Sol. (b)* **117**, 417 (1983)
91. K.B. Wiberg, *Tetrahedron* **24**, 1083 (1968)
92. V.A. Veryazov, A.V. Leko, R.A. Evarestov, *Phys. Solid State* **41**, 1286 (1999)
93. R.A. Evarestov, I.I. Tupitsyn, *Russ. J. Phys. Chem.* **74**, S363 (2000)
94. C. Pisani, E. Apra, M. Causa, *Int. J. Quant. Chem.* **38**, 419 (1990)
95. T. Bredow, R.A. Evarestov, K. Jug, *Phys. Stat. Sol. (b)* **222**, 495 (2000)
96. V. Fock, M. Vesselow, M. Petrashen, *Zh. Exsp. Theor. Fiz.* **10**, 723 (1940)
97. C.J. Cramer, *Essentials of Computational Chemistry*, 2nd edn. (Wiley, New York, 2004)
98. M.J. Wong, L. Radom, *J. Phys. Chem.* **99**, 8582 (1995)
99. C. Moller, M.S. Plesett, *Phys. Rev.* **46**, 618 (1934)
100. Per-Olov Löwdin, *Int. J. Quant. Chem.* **55**, 77 (1995)
101. P. Knowles, M. Schütz, H.-J. Werner, in *Proceedings of Modern Methods and Algorithms of Quantum Chemistry*, vol. 3, 2nd edn., ed. by J. Grotendorst (John von Neumann Institute for Computing, Jülich, NIC Series, 2000), p. 97
102. Gaussian 03, Revision C.02, M.J. Frisch, G.W. Trucks, H.B. Schlegel, G.E. Scuseria, M.A. Robb, J.R. Cheeseman, J.A. Montgomery Jr., T. Vreven, K.N. Kudin, J.C. Burant, J.M. Millam, S.S. Iyengar, J. Tomasi, V. Barone, B. Mennucci, M. Cossi, G. Scalmani, N. Rega, G.A. Petersson, H. Nakatsuji, M. Hada, M. Ehara, K. Toyota, R. Fukuda, J. Hasegawa, M. Ishida, T. Nakajima, Y. Honda, O. Kitao, H. Nakai, M. Klene, X. Li, J.E. Knox, H.P. Hratchian, J.B. Cross, V. Bakken, C. Adamo, J. Jaramillo, R. Gomperts, R.E. Stratmann, O. Yazyev, A.J. Austin, R. Cammi, C. Pomelli, J.W. Ochterski, P.Y. Ayala,

- K. Morokuma, G.A. Voth, P. Salvador, J.J. Dannenberg, V.G. Zakrzewski, S. Dapprich, A.D. Daniels, M.C. Strain, O. Farkas, D.K. Malick, A.D. Rabuck, K. Raghavachari, J.B. Foresman, J.V. Ortiz, Q. Cui, A.G. Baboul, S. Clifford, J. Cioslowski, B.B. Stefanov, G. Liu, A. Liashenko, P. Piskorz, I. Komaromi, R.L. Martin, D.J. Fox, T. Keith, M.A. Al-Laham, C.Y. Peng, A. Nanayakkara, M. Challacombe, P.M.W. Gill, B. Johnson, W. Chen, M.W. Wong, C. Gonzalez, J.A. Pople, Gaussian, Inc., Wallingford CT, 2004, <http://www.gaussian.com/citation.htm>
103. C. Pisani, M. Busso, G. Capecchi, S. Casassa, R. Dovesi, L. Maschio, C. Zicovich-Wilson, M. Schutz, *J. Chem. Phys.* **122**, 094113 (2005)
 104. P. Fulde, *Adv. Phys.* **51**, 909 (2002)
 105. H. Stoll, *Chem. Phys. Lett.* **191**, 548 (1992)
 106. A. Shukla, M. Dolg, P. Fulde, H. Stoll, *Phys. Rev. B* **60**, 5211 (1999)
 107. B. Paulus, *Chem. Phys. Lett.* **371**, 7 (2003)
 108. P. Fulde, H. Stoll, *Found. Phys.* **30**, 2049 (2000)
 109. K.N. Kudin, G.E. Scuseria, *J. Chem. Phys.* **113**, 7779 (2000)
 110. B.O. Roos, *Acc. Chem. Res.* **32**, 137 (1999)
 111. J. Cizek, *J. Chem. Phys.* **45**, 4256 (1966)
 112. T.D. Crawford, J. Stanton, *Int. J. Quant. Chem.* **70**, 601 (1998)
 113. K. Raghavachari, G.W. Trucks, J.A. Pople, M. Head-Gordon, *Chem. Phys. Lett.* **157**, 479 (1989)
 114. K.L. Bak, A. Halkier, P. Jorgensen, J. Olsen, T. Helgaker, W. Klopper, J. Mol. Structure (Theochem) **567–568**, 375 (2001)
 115. K. Hald, A. Halkier, P. Jorgensen, S. Horiani, S. Hättig, L. Helgaker, *J. Chem. Phys.* **118**, 2985 (2003)
 116. M. Kallay, J. Gauss, *J. Chem. Phys.* **120**, 6841 (2004)
 117. Y. He, D. Cremer, *Mol. Phys.* **98**, 1415 (2000)
 118. M.S. Lee, P.E. Masien, M. Head-Gordon, *J. Chem. Phys.* **112**, 3592 (2000)
 119. C. Hampel, H.-J. Werner, *J. Chem. Phys.* **104**, 6286 (1996)
 120. P.Y. Ayala, G.E. Scuseria, *J. Chem. Phys.* **110**, 3660 (1999)
 121. P. Pulay, S. Sacho, *Theor. Chim. Acta* **69**, 357 (1986)
 122. M. Schütz, G. Hetzer, H.-J. Werner, *J. Chem. Phys.* **111**, 5691 (1999)
 123. P. Knowles, M. Schutz, H.-J. Werner, in *Proceedings of Modern Methods and Algorithms of Quantum Chemistry*, vol. 3, 2nd edn., ed. by J. Grotendorst, NIC Series (John von Neumann Institute for Computing, Juelich, 2000), p. 97
 124. M. Schütz, *J. Chem. Phys.* **114**, 661 (2001)
 125. M. Schütz, *J. Chem. Phys.* **116**, 8772 (2002)
 126. S. Goedecker, G. Scuseria, *Comput. Sci. Eng.* **5**(4), 14 (2003)
 127. S. Saebo, P. Pulay, *J. Chem. Phys.* **86**, 914 (1987)
 128. M. Haser, J. Almlöf, *J. Chem. Phys.* **96**, 489 (1992)
 129. P. Constans, G.E. Scuseria, *Collect. Czech. Chem. Commun.* **68**, 357 (2003)
 130. M. Schütz, H.-J. Werner, R. Lindh, F.R. Manby, *J. Chem. Phys.* **121**, 737 (2004)
 131. A. Hesselmann, G. Jansen, M. Schütz, *J. Chem. Phys.* **122**, 014103 (2005)
 132. M. Schütz, G. Rauhut, H.-J. Werner, *J. Phys. Chem. A* **102**, 5997 (1998)
 133. M. Schütz, *Phys. Chem. Chem. Phys.* **4**, 3941 (2002)
 134. G.E. Scuseria, P.Y. Ayala, *J. Chem. Phys.* **111**, 8330 (1999)
 135. J.W. Boughton, P. Pulay, *J. Comput. Chem.* **14**, 736 (1993)
 136. G. Hetzer, P. Pulay, H.-J. Werner, *Chem. Phys. Lett.* **290**, 143 (1998)
 137. H.-J. Werner, F.R. Manby, P.J. Knowles, *J. Chem. Phys.* **118**, 8149 (2003)
 138. M. Shütz, F.R. Manby, *Phys. Chem. Chem. Phys.* **5**, 3349 (2003)
 139. F. Weigend, M. Häser, *Theor. Chim. Acta* **97**, 331 (1997)
 140. M. Schütz, *J. Chem. Phys.* **113**, 9986 (2000)
 141. W. Heitler, F. London, *Z. Phys.* **44**, 455 (1927)
 142. *Strong Coulomb Correlations in Electronic Structure Calculations. Beyond the Local Density Approximation*, ed. by Vladimir I. Anisimov (Gordon and Breach, Amsterdam, 2000)

143. J.P. Perdew, A. Zunger, Phys. Rev. B **23**, 5048 (1991)
144. V.I. Anisimov, J. Zaanen, O.K. Andersen, Phys. Rev. B **44**, 943 (1991)
145. C. Pisani, J. Molec. Structure (Theochem) **621**, 141 (2003)
146. C.M. Zicovich-Wilson, R. Dovesi, Chem. Phys. Lett. **277**, 227 (1997)
147. D.E. Usvyat, M. Schütz, Theor. Chem. Acc. **114**, 276 (2005)
148. A. Shukla, M. Dolg, H. Stoll, P. Fulde, Phys. Rev. B **57**, 1471 (1998)
149. B. Paulus, P. Fulde, H. Stoll, Phys. Rev. B **51**, 10572 (1995)
150. B. Paulus, Phys. Report **428**, 1 (2006)
151. W. Kutzelnigg, in *Methods of Electronic Structure Theory*, ed. by H.F. Schaefer III (Plenum, New York, 1977), p. 129
152. H. Stoll, B. Paulus, P. Fulde, J. Chem. Phys. **123**, 144108 (2005)
153. B. Paulus, P. Fulde, H. Stoll, Phys. Rev. B **54**, 2556 (1996)
154. M. Albrecht, B. Paulus, H. Stoll, Phys. Rev. B **56**, 7339 (1997)
155. K. Doll, M. Dolg, P. Fulde, H. Stoll, Phys. Rev. B **52**, 4842 (1995)
156. K. Doll, M. Dolg, H. Stoll, Phys. Rev. B **54**, 13529 (1996)
157. K. Doll, M. Dolg, P. Fulde, H. Stoll, Phys. Rev. B **55**, 10282 (1997)
158. K. Doll, H. Stoll, Phys. Rev. B **57**, 4327 (1998)
159. K. Rosciszewski, K. Doll, B. Paulus, P. Fulde, H. Stoll, Phys. Rev. B **57**, 14667 (1998)
160. K. Rosciszewski, B. Paulus, P. Fulde, H. Stoll, Phys. Rev. B **60**, 7905 (1999)
161. K. Rosciszewski, B. Paulus, P. Fulde, H. Stoll, Phys. Rev. B **62**, 5482 (2000)
162. B. Paulus, K. Rosciszewski, N. Gaston, P. Schwerdtfeger, H. Stoll, Phys. Rev. B **70**, 165106 (2004)
163. N. Gaston, B. Paulus, K. Rosciszewski, P. Schwerdtfeger, H. Stoll, Phys. Rev. B **74**, 094102 (2006)
164. S. Kalvoda, M. Dolg, H.-J. Flad, P. Fulde, H. Stoll, Phys. Rev. B **57**, 2127 (1998)
165. E. Voloshina, B. Paulus, Theor. Chem. Acc. **114**, 259 (2005)
166. J. Gräfenstein, H. Stoll, P. Fulde, Chem. Phys. Lett. **215**, 611 (1993)
167. J. Gräfenstein, H. Stoll, P. Fulde, Phys. Rev. B **55**, 13588 (1997)
168. M. Albrecht, P. Reinhardt, J.-P. Malrieu, Theor. Chem. Acc. **100**, 241 (1998)
169. A. Abdurahman, M. Albrecht, A. Shukla, M. Dolg, J. Chem. Phys. **110**, 8819 (1999)
170. M. Albrecht, P. Fulde, H. Stoll, Chem. Phys. Lett. **319**, 355 (2000)
171. A. Shukla, M. Dolg, P. Fulde, H. Stoll, Phys. Rev. B **57**, 1471 (1998)
172. R. Orlando, R. Dovesi, C. Roetti, V.R. Saunders, J. Phys. Condens. Matter **2**, 7769 (1990)
173. P. Fulde, Theor. Chem. Acc. **114**, 255 (2005)
174. J.Q. Sun, R.J. Bartlett, J. Chem. Phys. **104**, 8553 (1996)
175. P.Y. Ayala, K.N. Kudin, G.E. Scuseria, J. Chem. Phys. **115**, 9698 (2001)
176. J. Almlöf, Chem. Phys. Lett. **181**, 319 (1991)
177. M. Haser, Theor. Chim. Acta **87**, 147 (1993)
178. R. Pino, G.E. Scuseria, J. Chem. Phys. **121**, 2553 (2004)
179. P.Y. Ayala, G.E. Scuseria, Chem. Phys. Lett. **322**, 213 (2000)
180. A. Zunger, A. Katzir, A. Halperin, Phys. Rev. B **13**, 5560 (1976)
181. K. Kobayashi, T. Sano, Y. I'Haya, Chem. Phys. Lett. **219**, 53 (1994)
182. C. Pisani, G. Capecchi, S. Casassa, L. Maschio, Mol. Phys. **103**, 2527 (2005)
183. W. Boughton, P. Pulay, J. Comput. Chem. **14**, 736 (1993)
184. W. Kohn, Phys. Rev. **115**, 809 (1959)
185. P.W. Anderson, Phys. Rev. Lett. **21**, 13 (1968)
186. P. Zeiner, R. Dirl, B.L. Davies, Phys. Rev. B **58**, 7681 (1998)
187. L. He, D. Vanderbilt, Phys. Rev. Lett. **86**, 5341 (2001)
188. R.A. Evarestov, D.E. Usvyat, V.P. Smirnov, Phys. Solid State **45**, 2072 (2003)
189. S. Lui, J.M. Perez-Jorda, W. Yang, J. Chem. Phys. **112**, 1634 (2000)
190. H. Feng, J. Bian, L. Li, W. Yang, J. Chem. Phys. **120**, 9458 (2004)
191. S. Casassa, C.M. Zicovich-Wilson, C. Pisani, Theor. Chem. Acc. **116**, 726 (2006)
192. C.M. Zicovich-Wilson, R. Dovesi, Int. J. Quant. Chem. **67**, 299 (1998)
193. C.M. Zicovich-Wilson, R. Dovesi, V.R. Saunders, J. Chem. Phys. **115**, 9708 (2001)

194. R. Hoffmann, *J. Chem. Phys.* **39**, 1397 (1963)
195. J.A. Pople, D.L. Beveridge, *Approximate Molecular Orbital Theory* (McGraw-Hill, NY, 1970)
196. E.B. Moore, C.M. Carlson, *Phys. Rev. B* **4**, 2063 (1971)
197. R. Dovesi, C. Pisani, F. Ricca, C. Roetti, *Chem. Phys. Lett.* **39**, 103 (1976)
198. A.R. Leach, *Molecular Modelling: Principles and Applications*, 2nd edn. (Pearson Education EMA, Wiley, New York, 2001)
199. R. Canadine, I. Hiller, *J. Chem. Phys.* **50**, 2985 (1969)
200. J.C. Slater, *Phys. Rev.* **36**, 57 (1930)
201. J. Hinze, H.H. Jaffe, *J. Am. Chem. Soc.* **84**, 540 (1962)
202. L.C. Cusachs, J.W. Reynolds, D. Barnard, *J. Chem. Phys.* **44**, 835 (1966)
203. M. Wolfsberg, L.J. Helmholz, *J. Chem. Phys.* **20**, 837 (1952)
204. M. Nishida, *Phys. Rev. B* **58**, 7103 (1998)
205. J.R. Chelikowsky, M.L. Cohen, *Phys. Rev. B* **10**, 5095 (1974)
206. J. Cerda, F. Soria, *Phys. Rev. B* **61**, 7965 (2000)
207. A. Herman, *Modeling Simul. Mater. Sci. Eng.* **12**, 21 (2004)
208. W. Koch, B. Frey, J.F.S. Ruiz, T. Scior, *Z. Naturforsch.* **58a**, 756 (2003)
209. K. Ruedenberg, *J. Chem. Phys.* **19**, 1433 (1951)
210. R.S. Mulliken, *J. Chim. Phys.* **46**, 500, 521 (1949)
211. R. Fenske, K. Caulton, D. Radtke, C. Sweeney, *Inorg. Chem.* **5**, 951 (1966)
212. R.A. Evarestov, A.N. Ermoshkin, *Phys. Stat. Sol. (b)* **86**, 47 (1978)
213. W. Koch, B. Frey, J.F.S. Ruiz, T. Scior, *Z. Naturforsch.* **58a**, 785 (2003)
214. A.N. Ermoshkin, E.A. Kotomin, A.L. Shluger, *J. Phys. C Solid State Phys.* **15**, 847 (1982)
215. P.O. Löwdin, *J. Chem. Phys.* **18**, 365 (1950)
216. A.N. Ermoshkin, E.A. Kotomin, R.A. Evarestov, *Phys. Stat. Sol. (b)* **72**, 787 (1975)
217. G.A. Bordovskii, M.L. Gordeev, A.N. Ermoshkin, R.A. Evarestov, *Phys. Stat. Sol. (b)* **111**, K123 (1982)
218. R.A. Evarestov, A.N. Ermoshkin, V.A. Lovchikov, *Phys. Stat. Sol. (b)* **99**, 387 (1980)
219. A.N. Ermoshkin, R.A. Evarestov, *Optica i Spectroskopija* **35**, 786 (1973)
220. A.N. Ermoshkin, R.A. Evarestov, *Phys. Stat. Sol. (b)* **66**, 687 (1974)
221. A.N. Ermoshkin, R.A. Evarestov, E.A. Kotomin, *Phys. Stat. Sol. (b)* **73**, 81 (1976)
222. R.A. Evarestov, A.N. Ermoshkin, *Optica i Spectroskopija* **40**, 610 (1976)
223. R.A. Evarestov, A.N. Ermoshkin, E.A. Kotomin, *Phys. Stat. Sol. (b)* **73**, 483 (1976)
224. A.N. Ermoshkin, E.A. Kotomin, R.A. Evarestov, *Phys. Stat. Sol. (b)* **103**, 581 (1981)
225. T. Bredow, K. Jug, *Theor. Chem. Acc.* **113**, 1 (2005)
226. J.A. Pople, D.P. Santry, G.A. Segal, *J. Chem. Phys.* **43**, S129 (1965)
227. R. Pariser, G.R. Parr, *J. Chem. Phys.* **21**, 466, 767 (1953)
228. N. Mataga, K. Nishimoto, *Z. Phys. Chem.* **13**, 140 (1957)
229. K. Ohno, *Adv. Quant. Chem.* **3**, 240 (1967)
230. M.G. Veselov, M.M. Mestechkin, *Theor. Exp. Chem.* **6**, 471 (1973)
231. J.A. Pople, D.L. Beveridge, P.A. Dobosh, *J. Chem. Phys.* **47**, 2026 (1967)
232. Da Motta Neto, M.C. Zerner, *Int. J. Quant. Chem.* **81**, 187 (2001)
233. J.E. Ridley, M.C. Zerner, *Theor. Chim. Acta* **32**, 111 (1973)
234. M. Kotzian, N. Rosch, M.C. Zerner, *Theor. Chim. Acta* **81**, 201 (1992)
235. R.C. Bingham, M.J.S. Dewar, D.H. Lo, *J. Am. Chem. Soc.* **97**, 1285, 1307 (1975)
236. M.J.S. Dewar, E.G. Zoebisch, E.F. Healey, J.J.P. Stewart, *J. Am. Chem. Soc.* **107**, 3902 (1985)
237. W. Thiel, *J. Am. Chem. Soc.* **103**, 1413, 1421 (1981)
238. J.J.P. Stewart, *J. Comput. Chem.* **10**, 209 (1989)
239. D.N. Nanda, K. Jug, *Theor. Chim. Acta* **57**, 95 (1980)
240. K. Jug, R. Iffert, J. Schulz, *Int. J. Quant. Chem.* **32**, 265 (1987)
241. J. Li, P. Correa de Mello, K. Jug, *J. Comput. Chem.* **13**, 85 (1992)
242. M.C. Zerner, *Mol. Phys.* **23**, 963 (1972)
243. B. Ahlswede, K. Jug, *J. Comput. Chem.* **20**, 563 (1999)

244. B. Ahlswede, K. Jug, J. Comput. Chem. **20**, 572 (1999)
245. K. Jug, G. Geudtner, T. Homann, J. Comput. Chem. **21**, 974 (2000)
246. T. Bredow, G. Geudtner, K. Jug, J. Comput. Chem. **22**, 861 (2001)
247. T. Bredow, K. Jug, in *Encyclopedia of Computational Chemistry (online edition)*, ed. by P. Schleyer, N.L. Allinger, T. Clark, J. Gasteiger, P.A. Kollman, H.F. Schaefer III, P.R. Schreiner (Wiley, Chichester, 2004)
248. J. Schultz, R. Iffert, K. Jug, Int. J. Quant. Chem. **27**, 461 (1985)
249. B. Voigt, Theor. Chim. Acta **31**, 289 (1973)
250. C. Kollmar, M.C. Böhm, Theor. Chim. Acta **92**, 13 (1995)
251. C. Kollmar, Chem. Phys. Lett. **269**, 215 (1997)
252. C. Kollmar, B.A. Hess, Mol. Phys. **100**, 1945 (2002)
253. H. Fujita, A. Imamura, J. Chem. Phys. **53**, 4555 (1970)
254. S. O'Shea, D.P. Santry, J. Chem. Phys. **54**, 2667 (1971)
255. K. Mororuma, J. Chem. Phys. **54**, 962 (1971)
256. B.J. McAloon, P.G. Perkins, J. Chem. Soc. Faraday Trans. II **68**, 1121, 1833 (1972)
257. D.L. Beveridge, I. Jano, J. Ladik, J. Chem. Phys. **56**, 4744 (1972)
258. M.C. Böhm, Theor. Chim. Acta **62**, 351, 373 (1983)
259. M.J.S. Dewar, K.M. Merz Jr., Organometallics **5**, 1494 (1986)
260. J.J.P. Stewart, New Polym. Mater. **1**, 53 (1987)
261. J. Chandrasekhar, P.K. Das, J. Phys. Chem. B **96**, 679 (1992)
262. L.Y.A. Davila, M.J. Caldas, J. Comput. Chem. **23**, 1135 (2002)
263. F. Ricca, J. Phys. (Paris) **38**(Suppl.C-4), 173 (1977)
264. R. Dovesi, C. Pisani, F. Ricca, C. Roetti, Surf. Sci. **75**, 316 (1978)
265. R. Dovesi, C. Pisani, F. Ricca, C. Roetti, J. Chem. Phys. **65**, 3075, 4116 (1976)
266. R.A. Evarestov, V.A. Lovchikov, Phys. Stat. Sol. (b) **79**, 743 (1977)
267. A.H. Harker, F.P. Larkins, J. Phys. C Solid State Phys. **12**, 2487 (1979)
268. R. Dovesi, C. Pisani, C. Roetti, Surf. Sci. **103**, 482 (1981)
269. P.G. Perkins, A.K. Marwaha, J.J.P. Stewart, Theor. Chim. Acta **57**, 1 (1980)
270. P.V. Smith, J.E. Szymanski, J.A.D. Matthew, J. Phys. Solid State Phys. **18**, 3157 (1985)
271. R. Ramirez, M.C. Böhm, Int. J. Quant. Chem. **34**, 47 (1988)
272. R. Dovesi, C. Pisani, C. Roetti, J.M. Ricart, F. Illas, Surf. Sci. **148**, 225 (1984)
273. B.I. Craig, P.V. Smith, Surf. Sci. **210**, 468 (1989)
274. J.D. Weibel, D. Yaron, J. Chem. Phys. **116**, 6846 (2002)
275. A.J. Bennett, B. McCarroll, R.P. Messmer, Phys. Rev. B **3**, 1397 (1971)
276. A. Zunger, J. Phys. C: Solid State Phys. **7**, 76 (1974)
277. A. Zunger, J. Chem. Phys. **62**, 1861 (1975)
278. R.P. Messmer, G.D. Watkins, *Radiation Damage and Defects in Semiconductors*, vol. N16 (Institute of Physics, London, 1973) p. 255
279. A.M. Dobrotvorskii, R.A. Evarestov, Phys. Stat. Sol. (b) **66**, 83 (1974)
280. R.A. Evarestov, M.I. Petrashen, E.M. Ledovskaya, Phys. Stat. Sol. (b) **76**, 377 (1976)
281. *Hartree-Fock-Slater Method for Materials Science. The DV-X Alpha Method for Design and Characterization of Materials*, ed. by H. Adachi, T. Mukoyama, J. Kawai. Springer Series in Materials Science, vol. 84 (Springer, Berlin, 2006)
282. U. Lindefeldt, J. Phys. C Solid State Phys. **11**, 85 (1978)
283. P. Deak, L. Snyder, Phys. Rev. B **36**, 9619 (1987)
284. P. Deak, Phys. Stat. Sol. (b) **217**, 9 (2000)
285. R.A. Evarestov, M.I. Petrashen, E.M. Ledovskaya, Phys. Stat. Sol. (b) **68**, 453 (1975)
286. V.A. Koptsik, R.A. Evarestov, Kristallographia **25**, 5 (1980)
287. R.A. Evarestov, A.V. Leko, V.P. Smirnov, Phys. Stat. Sol. (b) **128**, 275 (1985)
288. P.G. Perkins, J.J.P. Stewart, J. Chem. Soc. Faraday II **76**, 520, 534 (1980)
289. J.J.P. Stewart, J. Comput. Chem. **19**, 168 (1998)
290. R.A. Evarestov, V.A. Lovchikov, Phys. Stat. Sol. (b) **93**, 469 (1979)
291. T. Bredow, G. Geudtner, K. Jug, Int. J. Quant. Chem. **22**, 89 (2001)
292. F. Janetzko, T. Bredow, K. Jug, J. Chem. Phys. **116**, 8994 (2002)

293. P. Deak, Phys. Lett. A **83**, 39 (1981)
294. A.L. Shluger, E.A. Kotomin, Phys. Stat. Sol. (b) **108**, 673 (1981)
295. R.A. Evarestov, V.A. Veryazov, Phys. Stat. Sol. (b) **157**, 281 (1990)
296. R.A. Evarestov, V.A. Veryazov, Rev. Solid State Sci. **5**, 415 (1991)
297. J. Noga, P. Banacký, S. Biskupic, R. Boca, P. Pelikan, M. Svrcek, A. Zajac, Int. J. Quant. Chem. **20**, 253 (1999)
298. P. Pelikan, J. Noga, S. Biskupic, J. Solid State Chem. **174**, 233 (2003)
299. E. Stefanovich, E. Shidlovskaya, A. Schluger, Phys. Stat. Sol. (b) **160**, 529 (1990)
300. S.S. Moliver, Phys. Solid State **42**, 673 (2000)
301. A.O. Litinskii, I.P. Zakharov, J. Struct. Chem. **27**, 517 (1986)
302. J.J.P. Stewart, J. Molec. Struct. (Theochem) **556**, 59 (2000)
303. A. Schluger, Theor. Chim. Acta **66**, 355 (1985)
304. A.H. Harker, F.P. Larkins, J. Phys. C Solid State Phys. **12**, 2509 (1979)
305. E.A. Kotomin, A.L. Schluger, Phys. Stat. Sol. (b) **109**, 75 (1982)
306. A.H. Harker, F.P. Larkins, J. Phys. C Solid State Phys. **12**, 2497 (1979)
307. P.V. Smith, J.E. Szymanski, J.A.D. Matthew, Phys. Stat. Sol. (b) **136**, 261 (1986)
308. R.A. Evarestov, V.A. Veryazov, Phys. Stat. Sol. (b) **158**, 201 (1990)
309. A. Porreda, V.A. Lovchikov, K. Jug, in *NATO ASI Series B, Cluster Models for Surface and Bulk Phenomena*, vol. 283, ed. by G. Pacchioni, P.S. Bagus, F. Parmigiani (Plenum, New York, 1992), p. 641
310. K. Jug, T. Bredow, J. Comput. Chem. **25**, 1551 (2004)
311. K. Jug, T. Bredow, in *Methods and Techniques in Computational Chemistry, METECC-95*, ed. by E. Clementi (STEF, Calgari, 1995), p. 89
312. R. Dovesi, V.R. Saunders, C. Roetti, N.M. Harrison, R.Orlando, E. Apra, *Crystal95 User's Manual* (Universita di Torino, Torino, 1996)
313. B. Silvi, N. Fouranti, R. Nada, C.R. Catlow, J. Phys. Chem. Solids **52**, 1005 (1991)
314. C. Pisani, R. Dovesi, C. Roetti, in *Hartree-Fock ab-initio Treatment of Crystalline Systems. Lecture Notes in Chemistry*, vol. 48 (Springer, Berlin, 1988)
315. L.H. Thomas, Proc. Camb. Philos. Soc. **23**, 542 (1927)
316. E. Fermi, Z. Phys. **48**, 73 (1928)
317. J.C. Slater, Phys. Rev. **91**, 528 (1953)
318. P. Hohenberg, W. Kohn, Phys. Rev. **136**, B864 (1964)
319. N.C. Handy, Molec. Phys. **102**, 2399 (2004)
320. K. Capelle, *A Birds-eye View of Density Functional Theory* (2005), <http://arXiv.org/archive/cond-mat/0211443v5>
321. W. Kohn, Rev. Mod. Phys. **71**, 1253 (1998)
322. W. Kohn, L.J. Sham, Phys. Rev. **140**, A1133 (1965)
323. R.M. Dreizler, E.K.U. Gross, *Density Functional Theory* (Springer, Berlin, 1990)
324. N.H. March, *Electron Density Theory of Atoms and Molecules* (Academic, London, 1992)
325. H. Eschrig, *The Fundamentals of Density Functional Theory* (Teubner, Leipzig, 1996)
326. *Density Functional Theory: Recent Progress and New Directions*, ed. by J.F. Dobson, G. Vignale, M.P. Das (Plenum, New York, 1998)
327. W. Koch, M.C. Holthausen, *A Chemist's Guide to Density Functional Theory*, 2nd edn. (Wiley, New York, 2002)
328. R.O. Jones, O. Gunnarsson, Rev. Mod. Phys. **61**, 689 (1989)
329. R. Neumann, Molec. Phys. **87**, 1 (1996)
330. J.P. Perdew, S. Kurth, Lect. Note Phys. **620**, 1 (2003)
331. K. Burke, J. Werschnik, E.K.U. Gross, J. Chem. Phys. **123**, 062206 (2005)
332. I.G. Kaplan, *Intermolecular Interactions. Physical Picture, Computational Methods and Model Potentials* (Wiley, New York, 2006)
333. K. Capelle, V.L. Libero, Int. J. Quant. Chem. **105**, 679 (2005)
334. J.C. Slater, Phys. Rev. **81**, 385 (1951)
335. P.A.M. Dirac, Proc. Camb. Philos. Soc. **26**, 376 (1930)
336. U. von Barth, L. Hedin, J. Phys. C Condens. Matter **5**, 1629 (1972)

337. O. Gunnarsson, B.I. Lundqvist, Phys. Rev. B **13**, 4274 (1976)
338. D.M. Ceperley, B.J. Alder, Phys. Rev. Lett. **45**, 566 (1980)
339. S.J. Vosko, L. Wilk, M. Nussair, Can. J. Phys. **1980**, 1200 (1980)
340. J.P. Perdew, A. Zunger, Phys. Rev. B **23**, 5048 (1981)
341. J.P. Perdew, Y. Wang, Phys. Rev. B **40**, 3389 (1989)
342. J.P. Perdew, A. Zunger, Phys. Rev. B **45**, 13244 (1992)
343. J.P. Perdew, A. Zunger, Phys. Rev. B **33**, 8800 (1986)
344. J.P. Perdew, K. Burke, M. Ernzerhof, Phys. Rev. Lett. **77**, 3865 (1996)
345. J.P. Perdew, A. Ruzsinszky, J. Tao, V.N. Staroverov, G.E. Scuseria, G.I. Csonka, J. Chem. Phys. **123**, 062201 (2005)
346. A.D. Becke, Phys. Rev. A **38**, 3098 (1988)
347. C. Lee, W. Wang, R.G. Parr, Phys. Rev. B **37**, 785 (1988)
348. J. Tao, J.P. Perdew, V.N. Staroverov, G.E. Scuseria, Phys. Rev. Lett. **91**, 146401 (2003)
349. Xin Xu, W.A. Goddard III, J. Chem. Phys. **121**, 4068 (2004)
350. J. Tao, J.P. Perdew, V.N. Staroverov, G.E. Scuseria, Phys. Rev. B **69**, 075102 (2004)
351. J.P. Perdew, S. Kurth, A. Zupan, P. Blaha, Phys. Rev. Lett. **82**, 2544 (1999)
352. J.P. Perdew, K. Burke, Y. Wang, Phys. Rev. B **54**, 16533 (1996)
353. P. Ziesche, S. Kurth, J.P. Perdew, Comput. Mater. Sci. **11**, 122 (1998)
354. E.H. Lieb, S. Oxford, Int. J. Quant. Chem. **19**, 427 (1981)
355. E.J. Baerends, O.V. Gritsenko, J. Chem. Phys. **123**, 062202 (2005)
356. M. Gruning, O.V. Gritsenko, E.J. Baerends, J. Chem. Phys. **118**, 7183 (2003)
357. E.J. Baerends, Phys. Rev. Lett. **87**, 133004 (2001)
358. M.A. Buijse, E.J. Baerends, Molec. Phys. **100**, 401 (2002)
359. F. Cora, M. Alfredsson, G. Mallia, D. Midlemiss, W.C. Mackrodt, R. Dovesi, R. Orlando, Struct. Bond. **113**, 171 (2004)
360. A.D. Becke, J. Chem. Phys. **112**, 4020 (2000)
361. A.D. Becke, J. Chem. Phys. **98**, 1372, 5468 (1993)
362. O.V. Gritsenko, P.R. T.Schipper, E.J. Baerends, Int. J. Quant. Chem. Symp. **30**, 1375 (1996)
363. J.P. Perdew, M. Ernzerhof, K. Burke, J. Chem. Phys. **105**, 9982 (1996)
364. J.E. Jaffe, A.C. Hess, J. Chem. Phys. **105**, 10983 (1996)
365. M.C. Payne, M.P. Teller, D.C. Allan, J.A. Arias, J.D. Joannopoulos, Rev. Mod. Phys. **64**, 1045 (1992)
366. K.N. Kudin, G.E. Scuseria, Phys. Rev. B **61**, 16440 (2000)
367. V.N. Staroverov, G.E. Scuseria, J. Tao, J.P. Perdew, Phys. Rev. B **69**, 075102 (2004)
368. L. Greengard, V. Rokhlin, J. Comput. Phys. **73**, 325 (1987)
369. K.N. Kudin, G.E. Scuseria, Chem. Phys. Lett. **289**, 611 (1998)
370. E. Artacho, D. Sanchez-Portal, P. Ordejon, A. Garcia, J.M. Soler, Phys. Stat. Sol. (b) **215**, 809 (1999)
371. P. Ordejon, E. Artacho, J.M. Soler, Phys. Rev. B **53**, R10441 (1996)
372. J.R. Chelikowsky, S.G. Loucie, Phys. Rev. B **29**, 3470 (1987)
373. G. Velde, E.J. Baerends, Phys. Rev. B **44**, 7888 (1991)
374. P.J. Feibelman, Phys. Rev. B **44**, 3916 (1991)
375. G. Seifert, D. Porezug, Th. Frauenheim, Int. J. Quant. Chem. **58**, 185 (1996)
376. M. Towler, A. Zupan, M. Causa, Comput. Phys. Commun. **98**, 181 (1996)
377. A. Lichanot, M. Merawa, M. Causa, Chem. Phys. Lett. **246**, 263 (1995)
378. A. Zupan, M. Causa, Int. J. Quant. Chem. **56**, 337 (1995)
379. A. Savin, Int. J. Quant. Chem. **S22**, 457 (1988)
380. A.D. Becke, J. Chem. Phys. **96**, 2155 (1992)
381. M. Causa, Lecture Notes in Chem. **48**, 91 (1996)
382. F. Figuerido, R.M. Levy, R. Zhou, B. Berne, J. Chem. Phys. **106**, 9835 (1997)
383. M. Challacombe, C. White, M. Head-Gordon, J. Chem. Phys. **107**, 1013 (1997)
384. K.N. Kudin, G.E. Scuseria, J. Chem. Phys. **121**, 2886 (2004)
385. K.N. Kudin, G.E. Scuseria, Phys. Rev. B **61**, 5141 (2000)
386. D.L. Strout, G.E. Scuseria, J. Chem. Phys. **102**, 8448 (1995)

387. J.M. Soler, E. Artacho, J.D. Gale, A. Garcia, J. Junquera, P. Ordejon, D. Sanchez-Portal, *J. Phys. Condens. Matter* **14**, 2745 (2002)
388. E. Anglada, J.M. Soler, J. Junquera, E. Artacho, *Phys. Rev. B* **66**, 205101 (2002)
389. M.C. Strain, G.E. Scuseria, M.J. Frisch, *Science* **271**, 51 (1996)
390. J.C. Burant, M.C. Strain, G.E. Scuseria, M.J. Frisch, *Chem. Phys. Lett.* **258**, 45 (1998)
391. P. Pulay, *J. Comput. Chem.* **3**, 556 (1982)
392. R.E. Stratmann, G.E. Scuseria, M.J. Frisch, *Chem. Phys. Lett.* **257**, 213 (1996)
393. C. Adamo, V. Barone, *J. Chem. Phys.* **110**, 6158 (1999)
394. J. Heyd, G.E. Scuseria, M. Ernzerhof, *J. Chem. Phys.* **118**, 8207 (2003)
395. J. Heyd, G.E. Scuseria, *J. Chem. Phys.* **120**, 7274 (2004)
396. W. Kohn, *Int. J. Quant. Chem.* **56**, 229 (1995)
397. J.P. Perdew, M. Ernzerhof, K. Burke, *J. Chem. Phys.* **105**, 9982 (1996)
398. M. Ernzerhof, G.E. Scuseria, *J. Chem. Phys.* **110**, 5029 (1999)
399. J.C. Burant, G.E. Scuseria, M.J. Frisch, *J. Chem. Phys.* **105**, 8969 (1996)
400. E. Schwegler, M. Challacombe, *J. Chem. Phys.* **105**, 2726 (1996)
401. C. Ochsenfeld, C.A. White, M. Head-Gordon, *J. Chem. Phys.* **109**, 1163 (1998)
402. M.W. Gill, J.A. Pople, *Int. J. Quant. Chem.* **40**, 753 (1991)
403. M. Ernzerhof, J.P. Perdew, *J. Chem. Phys.* **109**, 3313 (1998)
404. GAUSSIAN Development Version, Revision B.07, M.J. Frisch, G.W. Trucks, H.B. Schlegel, G.E. Scuseria, M.A. Robb, J.R. Cheeseman, J.A. Montgomery Jr., T. Vreven, K.N. Kudin, J.C. Burant, J.M. Millam, S.S. Iyengar, J. Tomasi, V. Barone, B. Mennucci, M. Cossi, G. Scalmani, N. Rega, G.A. Petersson, H. Nakatsuji, M. Hada, M. Ehara, K. Toyota, R. Fukuda, J. Hasegawa, M. Ishida, T. Nakajima, Y. Honda, O. Kitao, H. Nakai, M. Klene, X. Li, J.E. Knox, H.P. Hratchian, J.B. Cross, V. Bakken, C. Adamo, J. Jaramillo, R. Gomperts, R.E. Stratmann, O. Yazyev, A.J. Austin, R. Cammi, C. Pomelli, J.W. Ochterski, P.Y. Ayala, K. Morokuma, G.A. Voth, P. Salvador, J.J. Dannenberg, V.G. Zakrzewski, S. Dapprich, A.D. Daniels, M.C. Strain, O. Farkas, D.K. Malick, A.D. Rabuck, K. Raghavachari, J.B. Foresman, J.V. Ortiz, Q. Cui, A.G. Baboul, S. Clifford, J. Cioslowski, B.B. Stefanov, G. Liu, A. Liashenko, P. Piskorz, I. Komaromi, R.L. Martin, D.J. Fox, T. Keith, M.A. Al-Laham, C.Y. Peng, A. Nanayakkara, M. Challacombe, P.M.W. Gill, B. Johnson, W. Chen, M.W. Wong, C. Gonzalez, J.A. Pople (Gaussian Inc., Pittsburgh, PA, 2003)
405. J. Heyd, J.E. Peralta, G.E. Scuseria, R.L. Martin, *J. Chem. Phys.* **123**, 174101 (2005)
406. J. Uddin, G.E. Scuseria, *Phys. Rev. B* **72**, 035101 (2005)
407. J. Uddin, J.E. Peralta, G.E. Scuseria, *Phys. Rev. B* **71**, 155112 (2005)
408. I.D. Prodan, G.E. Scuseria, J.A. Sordo, K.N. Kudin, R.L. Martin, *J. Chem. Phys.* **123**, 014703 (2005)
409. V. Barone, J.E. Peralta, J. Uddin, G.E. Scuseria, *J. Chem. Phys.* **124**, 024709 (2006)
410. I.D. Prodan, G.E. Scuseria, R.L. Martin, *Phys. Rev. B* **73**, 045104 (2006)
411. J. Paier, R. Hirschl, M. Marsman, G. Kresse, *J. Chem. Phys.* **122**, 234102 (2005)
412. V.R. Saunders, R. Dovesi, C. Roetti, M. Causa, N.M. Harrison, R. Orlando, C.M. Zicovich-Wilson, *Crystal98 User's Manual* (University of Torino, Torino, 1998)
413. M.S. Hybertsen, S.G. Louie, *Phys. Rev. Lett.* **55**, 1418 (1985)
414. M.C. Foulkes, L. Mitás, R. Needs, G. Rajagopal, *Rev. Mod. Phys.* **73**, 33 (2001)
415. T. Bredow, A.R. Gerson, *Phys. Rev. B* **61**, 5194 (2000)
416. I. Moreira, F. Illas, R.L. Martin, *Phys. Rev. B* **65**, 155102 (2002)
417. W.C. Mackrodt, D.S. Middlemiss, T.G. Owens, *Phys. Rev. B* **69**, 115119 (2004)
418. F. Illas, R.L. Martin, *J. Chem. Phys.* **108**, 2519 (1998)
419. J. Muscat, A. Wander, N.M. Harrison, *Chem. Phys. Lett.* **342**, 397 (2001)
420. W.G. Aulbur, L. Johnson, J.W. Wilkins, *Solid State Phys.* **54**, 1 (2000)
421. F. Aryasetiawan, in *Strong Coulomb Correlations in Electronic Structure Calculations*, ed. by V.I. Anisimov (Gordon and Breach, Singapore, 2000), p. 1
422. J.P. Perdew, S. Kurth, A. Zupan, P. Blaha, *Phys. Rev. Lett.* **82**, 544 (1999)
423. L. Petit, A. Svane, Z. Szotek, W.M. Temmerman, *Phys. Rev. B* **72**, 205118 (2005)

424. T. Fujiwara, M. Arai, Y. Ishii, in *Strong Coulomb Correlations in Electronic Structure Calculations*, ed. by V.I. Anisimov (Gordon and Breach, Singapore, 2000), p. 167
425. V.I. Anisimov, A.I. Lichtenstein, in *Strong Coulomb Correlations in Electronic Structure Calculations*, ed. by V.I. Anisimov, (Gordon and Breach, Singapore, 2000), p. 97
426. V. Polo, E. Kraka, D. Cremer, *Molec. Phys.* **100**, 1771 (2002)
427. D. Cremer, *Molec. Phys.* **99**, 1899 (2001)
428. G.I. Csonka, B.J. Johnson, *Theor. Chem. Acc.* **99**, 158 (1998)
429. O.A. Vydrov, G.E. Scuseria, *J. Chem. Phys.* **121**, 8187 (2004)
430. O.A. Vydrov, G.E. Scuseria, *J. Chem. Phys.* **122**, 184107 (2005)
431. A. Svane, W.M. Temmerman, Z. Szotek, J. Laegsgaard, H. Winter, *Int. J. Quant. Chem.* **77**, 799 (2000)
432. A. Flipetti, N.A. Spaldin, *Phys. Rev. B* **67**, 125109 (2003)
433. M. Arai, T. Fujiwara, *Phys. Rev. B* **51**, 1477 (1995)
434. O.K. Anderson, *Phys. Rev. B* **12**, 3060 (1975)
435. M. Imada, A. Fujimori, Y. Tokura, *Rev. Mod. Phys.* **70**, 1040 (1998)
436. A. Rohrbach, J. Hafner, G. Kresse, *J. Phys. C Condens. Matter* **15**, 979 (2003)
437. G. Kresse, J. Furthmuller, *Comput. Mater. Sci.* **6**, 15 (1996)
438. G. Ricardo, F. Cora, A.A. Sokol, N.H. de Leeuw, C.R.A. Catlow, *Phys. Rev. B* **73**, 035116 (2006)
439. S.Z.N. Karazhanov, P. Ravindran, A. Kjekhus, H. Fjellvag, U. Grossner, B.G. Svensson, *J. Cryst. Growth* **287**, 162 (2006)
440. A.G. Eguiluz, O.D. Restrepo, B.C. Larson, J.Z. Tischler, P. Zschack, G.E. Jellison, *J. Phys. Chem. Solids* **66**, 2281 (2005)
441. R. Laskowskii, P. Blaha, K. Schwarz, *Phys. Rev. B* **67**, 075102 (2003)
442. A.L. Ivanovskii, T.I. Chupakhina, V.G. Zubkov, A.P. Tyutyunnik, V.N. Krasilnikov, G.V. Bazuev, S.V. Okatov, A.I. Lichtenstein, *Phys. Lett. A* **348**, 66 (2005)
443. Y. Wang, D.J. Doren, *Solid State Commun.* **136**, 142 (2005)
444. M. Towler, *An introductory guide to Gaussian basis sets in solid state electronic structure calculations* (2008), http://www.theochem.unito.it/crystal_tuto/mssc2008_cd/tutorials/index.html
445. A.D. McLean, R.S. McLean, Roothaan-Hartree-Fock atomic wave functions (Slater basis-set expansions for Z=55-92). *Atomic Data Nuclear Data Tables* **26**, 197 (1981)
446. S. Huzinaga, *J. Chem. Phys.* **42**, 1293 (1965)
447. M. Challacombe, J. Cioslowsky, *J. Chem. Phys.* **100**, 464 (1994)
448. T.H. Dunning, *J. Chem. Phys.* **90**, 1007 (1989)
449. K. Doll, N.M. Harrison, V.R. Saunders, *J. Phys. Condens. Matter* **11**, 5007 (1999)
450. J. Sauer, P. Ugliengo, E. Garrone, V.R. Saunders, *Chem. Rev.* **94**, 2095 (1994)
451. S.F. Boys, F. Bernardi, *Molec. Phys.* **19**, 553 (1970)
452. M. Gutowski, Jeanne G.C.M. van der Rijdt, J.H. van Lenthe, F.B. van Duijneveldt, *J. Chem. Phys.* **98**, 4728 (1993)
453. A. Gruneich, B.A. Hess, *Theor. Chem. Acc.* **100**, 253 (1998)
454. S.D. Kenny, A.P. Horsfield, H. Fujitami, *Phys. Rev. B* **62**, 4899 (2000)
455. A.P. Christiansen, Y.S. Lee, K.S. Pitzer, *J. Chem. Phys.* **71**, 4445 (1970)
456. D.R. Hamann, M. Schlüter, C. Chiang, *Phys. Rev. Lett.* **43**, 1494 (1979)
457. J.C. Phillips, L. Kleinman, *Phys. Rev.* **116**, 287 (1959)
458. L. Kleinman, D.M. Bylander, *Phys. Rev. Lett.* **48**, 1425 (1982)
459. M.I. Petrashen, I.V. Abarenkov, A.A. Berezin, R.A. Evarestov, *Phys. Stat. Sol. (b)* **40**, 9, 433 (1970)
460. I.V. Abarenkov, V. Heine, *Philos. Mag.* **12**, 529 (1965)
461. D. Vanderbilt, *Phys. Rev. B* **41**, 7892 (1990)
462. M. Fuchs, M. Scheffer, *Comput. Phys. Commun.* **119**, 67 (1999)
463. A. Alkauskas, A. Baratoff, C. Bruder, *J. Phys. Chem. A* **108**, 6863 (2004)
464. M. Krauss, W.J. Stevens, *Ann. Rev. Phys. Chem.* **35**, 357 (1984)

465. M. Dolg, in *Modern Methods and Algorithms of Quantum Chemistry*, ed. by J. Grotendost, NIC Series, vol. 1, 479 (2000), **3**, 507 (2000), online <http://www.fz-juelich.de/nic-series/NIC-Series-e.html>
466. A.V. Titov, N.S. Mosyagin, *Rus. J. Phys. Chem. [Zh. Phys. Khimii]*, **74**, (Suppl. 2) S376 (2000)
467. P.J. Hay, W.R. Wadt, *J. Chem. Phys.* **52**, 270, 284, 299 (1985)
468. P. Durand, J.C. Barthelat, *Theor. Chim. Acta* **38**, 283 (1975)
469. W.J. Stevens, H. Basch, M. Krauss, *J. Chem. Phys.* **81**, 6026 (1984)
470. W.J. Stevens, M. Krauss, H. Basch, P.J. Jasic, *Can. J. Phys.* **70**, 612 (1992)
471. H. Stoll, B. Metz, M. Dolg, *J. Comput. Chem.* **23**, 767 (2002)
472. I.V. Abarenkov, I.I. Tupitsyn, *J. Chem. Phys.* **115**, 1650 (2004)
473. *Electronic Properties of Solids Using Cluster Methods*, ed. by T.A. Kaplan, S.D. Mahanti, (Plenum Press, New York London, 1994)
474. I.V. Abarenkov, I.M. Antonova, *Int. J. Quant. Chem.* **100**, 649 (2004)
475. S. Goedecker, K. Maschke, *Phys. Rev. B* **42**, 8858 (1990)
476. P.E. Blochl, *Phys. Rev. B* **41**, 5414 (1999)
477. X. Gonze, R. Stumpf, M. Scheffer, *Phys. Rev. B* **44**, 8503 (1991)
478. A. Khein, *Phys. Rev. B* **51**, 16608 (1995)
479. X. Gonze, P. Käckell, M. Scheffer, *Phys. Rev. B* **41**, 12264 (1990)
480. T. Nakajima, T. Yanai, K. Hirao, *J. Comput. Chem.* **23**, 847 (2002)
481. *Relativistic Electronic Structure Theory, Part I, Fundamentals*, ed. by P. Schwerdtfeger, vol. 11 of Theoretical and Computational Chemistry (Elsevier, Amsterdam, 2002)
482. *Relativistic Electronic Structure Theory, Part II, Applications*, ed. by P. Schwerdtfeger, vol. 14. Theoretical and Computational Chemistry (Elsevier, Amsterdam, 2004)
483. T. Saue, T. Helgaker, *J. Comput. Chem.* **23**, 814 (2002)
484. A.K. Rajagopal, J. Callaway, *Phys. Rev. B* **7**, 1912 (1973)
485. C. van Wullen, *J. Comput. Chem.* **23**, 779 (2002)
486. K.G. Dyall, *J. Comput. Chem.* **23**, 786 (2002)
487. L. Visscher, *J. Comput. Chem.* **23**, 759 (2002)
488. L. Visscher, O. Visser, H. Aerts, H. Merenga, W.C. Nieuwport, *Comput. Phys. Commun.* **81**, 120 (1994)
489. T. Saue, K. Fargi, T. Helgaker, O. Gropen, *Molec. Phys.* **91**, 937 (1997)
490. I.P. Grant, H.M. Quiney, *Int. J. Quant. Chem.* **80**, 283 (2000)
491. W. Kutzelnigg, *Z. Phys. D* **15**, 27 (1990)
492. Y.S. Lee, W.C. Ermler, K.S. Pitzer, *J. Chem. Phys.* **67**, 5861 (1977)
493. E. Lenthe, E.J. Baerends, J.G. Snijders, *J. Chem. Phys.* **99**, 4597 (1993)
494. W.C. Ermler, R.B. Ross, P.A. Christiansen, *Adv. Quant. Chem.* **19**, 139 (1988)
495. P. Schwerdtfeger, in *Theoretical Chemistry and Physics of Heavy and Superheavy elements*, ed. by U. Kaldor, S. Wilson (Kluwer, Dordrecht, 2003)
496. A.N. Petrov, N.S. Mosyagin, A.V. Titov, I.I. Tupitsyn, *J. Phys. B* **37**, 4621 (2004)
497. K.G. Dyall, *J. Chem. Phys.* **100**, 2118 (1994)
498. A.V. Titov, N.S. Mosyagin, *Int. J. Quant. Chem.* **71**, 359 (1999)
499. G. Treurich, N.A. Hill, *Phys. Rev. B* **64**, 073106 (2001)
500. D. Figgen, G. Rauhut, M. Dolg, H. Stoll, *Chem. Phys.* **311**, 227 (2005)
501. M. Dolg, *Theor. Chem. Acc.* **114**, 297 (2005)
502. K.A. Peterson, C. Puzzarini, *Theor. Chem. Acc.* **114**, 283 (2005)
503. X. Cao, M. Dolg, *J. Mol. Struct. (Theochem)* **673**, 203 (2004)
504. X. Cao, M. Dolg, H. Stoll, *J. Chem. Phys.* **118**, 487 (2003)
505. V. Bonifacic, S. Huzinaga, *J. Chem. Phys.* **60**, 2779 (1974)
506. S. Katsuki, S. Huzinaga, *Chem. Phys. Lett.* **152**, 203 (1988)
507. L. Seijo, Z. Barandiaran in *Relativistic Electronic Structure Theory, Part II, Applications*, ed. by P. Schwerdtfeger, vol. 14 of Theoretical and Computational Chemistry (Elsevier, Amsterdam, 2004), p. 417
508. N.S. Mosyagin, A.V. Titov, E. Eliav, U. Kaldor, *J. Chem. Phys.* **115**, 2007 (2001)

509. N.S. Mosyagin, A.V. Titov, J. Chem. Phys. **122**, 234106 (2005)
510. L.F. Pacios, P.A. Christiansen, J. Chem. Phys. **82**, 2664 (1985)
511. M.G. Kozlov, V.I. Fomichev, Y.Y. Dmitriev, L.N. Labzovsky, A.V. Titov, J. Phys. B **20**, 4939 (1987)
512. Y.Y. Dmitriev, Y.G. Khait, M.G. Kozlov, L.N. Labzovsky, A.O. Mitrushenkov, A.V. Titov, Phys. Lett. A **167**, 280 (1992)
513. A.V. Titov, N.S. Mosyagin, V.F. Ezhov, Phys. Rev. Lett. **77**, 5346 (1996)
514. N.S. Mosyagin, M.G. Kozlov, A.V. Titov, J. Phys. B **31**, L763 (1998)
515. M.G. Kozlov, A.V. Titov, N.S. Mosyagin, P.V. Souschko, Phys. Rev. A **56**, R3326 (1997)
516. A.N. Petrov, N.S. Mosyagin, T.A. Isaev, A.V. Titov, V.F. Ezhov, E. Eliav, U. Kaldor, Phys. Rev. Lett. **88**, 073001 (2002)
517. T.A. Isaev, A.N. Petrov, N.S. Mosyagin, A.V. Titov, E. Eliav, U. Kaldor, Phys. Rev. A **69**, R03050 (2004)
518. A.N. Petrov, A.V. Titov, T.A. Isaev, N.S. Mosyagin, D.P. DeMolle, Phys. Rev. A **72**, 022505 (2005)
519. T.A. Isaev, N.S. Mosyagin, A.N. Petrov, A.V. Titov, Phys. Rev. Lett. **95**, 163004 (2005)
520. P.E. Blöchl, Phys. Rev. B **50**, 17953 (1994)
521. A.V. Titov, N.S. Mosyagin, A.N. Petrov, T.A. Isaev, Int. J. Quant. Chem. **104**, 223 (2005)
522. J. Almlöf, P.R. Taylor, J. Chem. Phys. **86**, 4070 (1987)
523. B. Liu, A.D. McLean, J. Chem. Phys. **91**, 2348 (1989)
524. A.V. Titov, Int. J. Quant. Chem. **45**, 7 (1993)
525. S. Suzuki, K. Nakao, J. Phys. Soc. Jpn. **68**, 1982 (1999)
526. J.C. Boettger, Phys. Rev. B **57**, 8743 (1998)
527. K. Kudin, G.E. Scuseria, R.L. Martin, Phys. Rev. Lett. **89**, 266402 (2002)
528. T. Tsuchiya, M. Abe, T. Nakajima, K. Hirao, J. Chem. Phys. **115**, 4463 (2001)
529. E. van Lenthe, E.J. Baerends, J. Comput. Chem. **24**, 1142 (2003)
530. J.C. Boettger, Eur. Phys. J. **36**, 15 (2003)
531. J.J. Ladik, J. Mol. Struct. (Theochem) **391**, 1 (1997)
532. M. Douglas, N.M. Kroll, Ann. Phys. **82**, 89 (1974)
533. B.A. Hess, Phys. Rev. A **33**, 3742 (1986)
534. J.E. Peralta, G.E. Scuseria, J. Chem. Phys. **120**, 5875 (2004)
535. T. Nakajima, K. Hirao, J. Chem. Phys. **113**, 7786 (2000)
536. A. Wolf, M. Reiher, B.A. Hess, J. Chem. Phys. **117**, 9215 (2002)
537. N.J.M. Geipel, B.A. Hess, Chem. Phys. Lett. **273**, 62 (1997)
538. J.C. Boettger, Phys. Rev. B **57**, 8743 (1998)
539. M.D. Jones, J.C. Boettger, R.C. Albers, D.J. Singh, Phys. Rev. B **61**, 4644 (2000)
540. J.C. Boettger, A.K. Ray, Int. J. Quant. Chem. **90**, 1470 (2002)
541. J.C. Boettger, Int. J. Quant. Chem. **95**, 380 (2003)
542. J.C. Boettger, Int. J. Quant. Chem. **100**, 845 (2004)
543. J. Yang, M. Dolg, Theor. Chem. Acc. **113**, 212 (2005)
544. E.R. Batista, R.L. Martin, P.J. Hay, J. Chem. Phys. **121**, 2144 (2004)
545. J.E. Peralta, J. Uddin, G.E. Scuseria, J. Chem. Phys. **122**, 084108 (2005)
546. P.H.T. Phillipsen, E. van Lenthe, J.G. Snijders, E.J. Baerends, Phys. Rev. B **56**, 13556 (2000)
547. P.H.T. Phillipsen, E.J. Baerends, Phys. Rev. B **61**, 1773 (2000)
548. D. Olguin, M. Cardona, A. Cantarero, Solid State Commun. **122**, 575 (2002)
549. M. Cardona, M.L. Thewalt, Revs. Mod. Phys. **77**, 1173 (2005)
550. L. Colombo, La Rivista del Nuovo Cimento **28**, 1 (2005)
551. C.M. Goringe, D.R. Bowler, E. Hernandez, Rep. Progr. Phys. **60**, 1447 (1997)
552. R. Dovesi, B. Civalieri, R. Orlando, C. Roetti, V.R. Saunders, Rev. Comput. Chem. **21**, 1 (2005)
553. S.G. Semenov, Vestnik LGU, **N16**, 119 (1973)
554. I. Mayer, Int. J. Quant. Chem. **29**, 73 (1986)
555. R.A. Evarestov, V.A. Veryazov, Theor. Chim. Acta **81**, 95 (1991)
556. R.A. Evarestov, V.A. Veryazov, Rev. Solid State Sci. **5**, 415 (1991)

557. R.C. Bochicchio, H.F. Reale, J.A. Medrano, *Phys. Rev. B* **40**, 7186 (1989)
558. V.A. Veryazov, A.V. Leko, R.A. Evarestov, *Phys. Solid State* **41**, 1286 (1999)
559. R.A. Evarestov, A.I. Panin, *Int. J. Quant. Chem.* **88**, 472 (2002)
560. R.C. Bochicchio, H.F. Reale, *J. Phys. B* **26**, 4871 (1993)
561. R.A. Evarestov, A.I. Panin, *Phys. Solid State* **42**, 59 (2000)
562. R.C. Bochicchio, *Theochem* **429**, 229 (1998)
563. R.C. Bochicchio, L. Lain, A. Torre, *J. Comput. Chem.* **24**, 1902 (2003)
564. R.C. Bochicchio, L. Lain, A. Torre, *Chem. Phys. Lett.* **374**, 567 (2003)
565. R.A. Evarestov, V.A. Veryazov, *Phys. Stat. Sol. (b)* **157**, 281, **158**, 201 (1990)
566. J. Choynet, R.A. Evarestov, I.I. Tupitsyn, V.A. Veryazov, *Phys. Stat. Sol. (b)* **179**, 441 (1993)
567. R.A. Evarestov, I.I. Tupitsyn, V.A. Veryazov, *Int. J. Quant. Chem.* **52**, 295 (1994)
568. J. Sichel, M.A. Whitehead, *Theor. Chim. Acta* **11**, 220 (1968)
569. I.D. Brown, *J. Solid State Chem.* **82**, 122 (1989)
570. I.D. Brown, *J. Chem. Educat.* **77**, 1070 (2000)
571. I.D. Brown, *J. Appl. Crystallogr.* **29**, 479 (1996)
572. I.D. Brown, in *Structure and Bonding in Crystals*, vol. 2 ed. by M.O. Keffe, A. Navrotsky, 1 (Academic, New York, 1981)
573. P. Marksteiner, P. Blaha, K. Schwarz, *Z. Phys. B Condens. Matter* **64**, 119 (1986)
574. W.Y. Ching, Y.N. Xu, K.W. Wong, *Phys. Rev. B* **40**, 7684 (1989)
575. P. Saalfrank, M.A. Abdel-Raouf, J. Ladik, R.F. Wood, *Phys. Rev. B* **41**, 8824 (1990)
576. G.H. Hander, P.J. Brown, J. Spalek, J.M. Monig, *Phys. Rev. B* **40**, 4463 (1989)
577. J. Choynet, J.M. Bassat, H. Pilliere, P. Odier, M. Leblanc, *Solid State Commun.* **66**, 1245 (1988)
578. I.D. Brown, *Acta Crystallogr. B* **48**, 553 (1992)
579. M. Crespín, C. Landorn, P. Odier, J.M. Bassat, P. Mouron, J. Choynet, *J. Solid State Chem.* **100**, 281 (1992)
580. P. Reinhardt, B.A. Hess, M. Causa, *Int. J. Quant. Chem.* **58**, 297 (1996)
581. J. Muscat, V. Swamy, N.M. Harrison, *Phys. Rev. B* **65**, 224112 (2002)
582. M. Catti, C. Sandrone, R. Dovesi, *Phys. Rev. B* **55**, 16122 (1997)
583. M. Catti, G. Sandrone, *Faraday Disc.* **106**, 189 (1997)
584. R.A. Evarestov, A.I. Panin, *Phys. Stat. Sol. (b)* **214**, R5 (1999)
585. M.D. Segall, R. Stah, C.J. Pickard, M.C. Payne, *Phys. Rev. B* **52**, 1005 (1996)
586. R.A. Evarestov, A.V. Leko, V.A. Veryazov, *Phys. Stat. Sol. (b)* **203**, R3 (1997)
587. R.A. Evarestov, D.E. Usvyat, V.P. Smirnov, *Solid State Commun.* **127**, 423 (2003)
588. R.A. Evarestov, D.E. Usvyat, V.P. Smirnov, *Phys. Solid State* **45**, 459 (2003)
589. R.A. Evarestov, V.P. Smirnov, D.E. Usvyat, *Theor. Chem. Acc.* **114**, 19 (2005)
590. S. Piskinov, E. Heifets, R. Eglitis, G. Borstel, *Comput. Mater. Sci.* **29**, 165 (2004)
591. M. Veithen, X. Gonze, M. Chosez, *Phys. Rev. B* **66**, 235113 (2002)
592. R.A. Evarestov, V.P. Smirnov, I.I. Tupitsyn, D.E. Usvyat, *Int. J. Quant. Chem.* **104**, 110 (2005)
593. W.C. Lu, C.Z. Wang, T.L. Chan, K. Ruedenberg, K.M. Ho, *Phys. Rev. B* **70**, 041101 (2004)
594. A. Bert, M. Llunell, R. Dovesi, C.M. Zicovich-Wilson, *Phys. Chem. Chem. Phys.* **5**, 5319 (2003)
595. R.A. Evarestov, I.I. Tupitsyn, A.V. Bandura, V.E. Alexandrov, *Int. J. Quant. Chem.* **106**, 2191 (2006)
596. V.P. Smirnov, R.A. Evarestov, *Phys. Rev. B* **72**, 075138 (2005)
597. R.A. Evarestov, A.V. Bandura, V.E. Alexandrov, *Phys. Solid State* **47**, 2248 (2005)
598. R.A. Evarestov, A.V. Bandura, V.E. Alexandrov, E.A. Kotomin, *Phys. Stat. Sol. (b)* **242**, R11 (2005)
599. S. Gennard, F. Cora, C.R.A. Catlow, *J. Phys. Chem. B* **103**, 10158 (1999)
600. E. Mete, R. Shattaf, S. Ellialtioglu, *Phys. Rev. B* **68**, 035119 (2003)
601. D. Sanchez-Portal, E. Artacho, J.M. Soler, *Solid State Commun.* **95**, 685 (1995)
602. D. Sanchez-Portal, E. Artacho, J.M. Soler, *J. Phys. Condens. Matter* **8**, 3859 (1995)
603. I.I. Tupitsyn, R.A. Evarestov, V.P. Smirnov, *Phys. Solid State* **47**, 1837 (2005)

604. C.Y. Ren, S.H. Chiou, J. Choisnet, J. Appl. Phys. **99**, 23706 (2006)
605. J.S. Lin, A. Quteish, M.C. Payne, V. Heine, Phys. Rev. B **47**, 4174 (1993)
606. E. Ruiz, S. Alvarez, P. Alemany, R. Evarestov, Phys. Rev. B **56**, 7189 (1997)
607. R.A. Evarestov, D.E. Usvyat, V.P. Smirnov, Phys. Solid State **45**, 2072 (2003)
608. P.A. Cox, *Transition Metal Oxides* (Carendon Press, Oxford, 1992)
609. C.N.R. Rao, B. Raveau, *Transition Metal Oxides* (VCH, New York, 1995)
610. W.E. Pickett, Rev. Mod. Phys. **61**, 433 (1989)
611. N.M. Harrison, V.R. Saunders, R. Dovesi, W.C. Mackrodt, A.S. Alexandrov, C.N.R. Rao, J.N. Murrell, R.L. Johnston, D.E. Logan, Philos. Trans. Roy. Soc. Lond. A **356**, 75 (1998)
612. M.D. Towler, N.L. Allan, N.M. Harrison, V.R. Saunders, W.C. Mackrodt, E. Apra, Phys. Rev. B **50**, 5041 (1994)
613. M. Catti, G. Valerio, R. Dovesi, Phys. Rev. B **51**, 7441 (1995)
614. M. Catti, G. Sandrone, G. Valerio, R. Dovesi, J. Phys. Chem. Solids **57**, 1735 (1996)
615. A. Chartier, P. D'Arco, R. Dovesi, V.R. Saunders, Phys. Rev. B **60**, 14042 (1999)
616. E. Ruiz, M. Llunell, P. Alemany, J. Solid State Chem. **176**, 400 (2003)
617. I.d.P.R. Moreira, R. Dovesi, Phys. Rev. B **67**, 134513 (2003)
618. Y.-S. Su, T.A. Kaplan, S.D. Mahanti, J.F. Harrison, Phys. Rev. B **61**, 1324 (2000)
619. M. Nicastro, C.H. Patterson, Phys. Rev. B **65**, 205111 (2002)
620. G. Trimarchi, N. Binggeli, Phys. Rev. B **71**, 035101 (2005)
621. P. Pavindra, A. Kjekshus, H. Fjellvag, A. Delin, O. Eriksson, Phys. Rev. B **65**, 064445 (2002)
622. D. Munoz, N.M. Harrison, F. Illas, Phys. Rev. B **69**, 085115 (2004)
623. R.A. Evarestov, E.A. Kotomin, Yu.A. Mastrikov, D. Gryaznov, E. Heifets, J. Maier, Phys. Rev. B **72**, 124411 (2005)
624. N.N. Kovaleva, A.V. Boris, C. Bernhard, A. Kulakov, A. Pimenov, A.M. Balbashov, G. Khaliullin, B. Keimer, Phys. Rev. Lett. **93**, 147204 (2004)
625. F. Moussa, M. Hennion, J. Rodriguez-Carvajal, H. Moudiden, L. Pinsard, A. Revcolevschi, Phys. Rev. B **54**, 15149 (1996)
626. N. Hamada, H. Sawada, I. Solov'yev, K. Terakura, Physica **B237–238**, 11 (1997)
627. R. Lorenz, R. Hafner, D. Spisak, J. Hafner, J. Magn. Reson. Ser. A **226–230**, 889 (2001)
628. P. Ravindran, A. Kjekshus, H. Fjellvag, A. Delin, O. Eriksson, Phys. Rev. B **65**, 064445 (2002)
629. T. Saitoh, A.E. Boquet, T. Mizokawa, H. Namatame, A. Fujimori, M. Abbate, Y. Takeda, M. Takano, Phys. Rev. B **51**, 13942 (1995)
630. T.H. Lonkai, D.G. Tomuta, U. Amann, J. Ihringer, R.W.A. Hendrikx, D.M. Tobben, J.A. Mydosh, Phys. Rev. B **69**, 134108 (2004)
631. M. Fiebig, D. Frolich, K. Kohn, St. Leute, T.H. Lottermoser, V.V. Pavlov, R.V. Pisarev, Phys. Rev. Lett. **84**, 5620 (2000)
632. D.G. Tomuta, S. Ramakrishnan, G.J. Nieuwenhuys, J.A. Mydosh, J. Phys.: Condens. Matter **13**, 4543 (2001)
633. C. Degenhardt, M. Fiebig, D. Frolich, T.H. Lottermoser, R.V. Pisarev, Appl. Phys. B **73**, 139 (2001)
634. M.C. Qian, J. Dong, Q. Cheng, Phys. Lett. A **270**, 96 (2000)
635. J.E. Medvedeva, V.I. Anisimov, M.A. Korotin, O.N. Mryasov, A.J. Freeman, J. Phys.: Condens. Matter **12**, 4947 (2000)
636. A.M. Kalashnikova, R.V. Pisarev, JETP Lett. **78**, 3 (2003)
637. T. Bredow, K. Jug, R.A. Evarestov, Phys. Stat. Sol. (b) **243**, R10 (2006)
638. M. Bieringer, J.E. Greedan, J. Solid State Chem. **143**, 132 (1999)
639. J. Park, J.-G. Park, G.S. Jeon, H.Y. Choi, C. Lee, W. To, R. Bewley, K.A. McEwen, T.G. Perring, Phys. Rev. B **68**, 104426 (2003)
640. P. Pulay, Mol. Phys. **17**, 197 (1969)
641. H.B. Schlegel, Theor. Chem. Acc. **103**, 294 (2000)
642. S. Hirata, H. Tori, M. Tatsumi, Phys. Rev. B **57**, 11994 (1998)
643. D. Jacquemin, J.M. Andre, B. Champagne, J. Chem. Phys. **111**, 5306–5324 (1999)

644. B. Civalleri, Ph. D'Arco, R. Orlando, V.R. Saunders, R. Dovesi, *Chem. Phys. Lett.* **348**, 131 (2001)
645. K. Doll, V.R. Saunders, N.M. Harrison, *Int. J. Quant. Chem.* **82**, 1 (2001)
646. K. Doll, *Comput. Phys. Commun.* **137**, 74 (2001)
647. K. Doll, R. Dovesi, R. Orlando, *Theor. Chem. Acc.* **112**, 394 (2004)
648. K. Doll, R. Dovesi, R. Orlando, *Theor. Chem. Acc.* **115**, 354 (2006)
649. R. Dovesi, *Lect. Note Chem.* **67**, 179 (1996)
650. K. Rosciszewski, K. Doll, B. Paulus, P. Fulde, *Phys. Rev. B* **57**, 14667 (1998)
651. *Handbook of Chemistry and Physics*, ed. R.C. Weast, (CRC, Boca Raton, FL 1987)
652. B.J. Kennedy, C.J. Howard, B.C. Chakoumakos, *Phys. Rev. B* **59**, 4023 (1999)
653. F. Pascale, C.M. Zicovich-Wilson, F. Lopez, B. Civalleri, R. Orlando, R. Dovesi, *J. Comput. Chem.* **25**, 888 (2004)
654. S. Baroni, S. de Gironcoli, A. Dal Corso, P. Giannozzi, *Rev. Mod. Phys.* **73**, 515 (2001)
655. K. Parlinski, Z.Q. Li, Y. Kawazoe, *Phys. Rev. Lett.* **78**, 4063 (1997)
656. P. Sikora, *J. Phys. Chem. Solids* **66**, 1069 (2005)
657. B. Montanari, B. Civalleri, C.M. Zicovich-Wilson, R. Dovesi, *Int. J. Quant. Chem.* **106**, 1703 (2006)
658. M. Principe, F. Pascale, C.M. Zicovich-Wilson, V.R. Saunders, R. Orlando, R. Dovesi, *Phys. Chem. Miner.* **31**, 559 (2004)
659. P. Umari, A. Pasquarello, A. Dal Corso, *Phys. Rev. B* **63**, 094305 (2001)
660. B. Montanari, N.M. Harrison, *Chem. Phys. Lett.* **364**, 528 (2002)
661. S. Na-Phattalung, M.F. Smith, K. Kim, M.H. Du, S.H. Wei, S.B. Zhang, S. Limpijumnong, *Phys. Rev. B* **73**, 125205 (2006)
662. R.A. Evarestov, in *Computational Materials Science*, NATO Science Series III, **187**, 122 (2003)
663. R.A. Evarestov, *Phys. Stat. Sol. (a)* **202**, 235 (2005)
664. R.A. Evarestov, S. Piskunov, E.A. Kotomin, G. Borstel, *Phys. Rev. B* **67**, 064101 (2003)
665. R.A. Evarestov, V.P. Smirnov, *Phys. Stat. Sol. (b)* **201**, 75 (1997)
666. R.A. Evarestov, P.W.M. Jacobs, A.V. Leko, *Phys. Rev. B* **54**, 8969 (1996)
667. R.A. Evarestov, V.P. Smirnov, *Phys. Stat. Sol. (b)* **215**, 949 (1999)
668. C. Freyria-Fava, R. Dovesi, V.R. Saunders, M. Leslie, C. Roetti, *J. Phys. Condens. Matter* **5**, 4793 (1993)
669. L.N. Kantorovich, J.M. Holender, M.J. Gillan, *Surf. Sci.* **343**, 221 (1995)
670. C.W.M. Castleton, S. Mirb, *Phys. Rev. B* **70**, 175202 (2004)
671. C. Pisani, *Phase Trans.* **52**, 123 (1994)
672. M. Leslie, M.J. Gillan, *J. Phys. C Solid State Phys.* **18**, 973 (1985)
673. G. Makov, M.C. Payne, *Phys. Rev. B* **51**, 4014 (1995)
674. J. Lento, J.L. Mozos, R.M. Nieminen, *J. Phys. Condens. Matter* **14**, 2637 (2002)
675. U. Gerstmann, P. Deak, R. Rurali, B. Aradi, TH. Frauenheim, H. Overhof, *Phys. B* **340–342**, 190 (2003)
676. C.W.M. Castleton, A. Hoglund, S. Mirbt, *Phys. Rev. B* **73**, 035215 (2006)
677. J. Shim, E. Lee, Y. Lee, R.M. Nieminen, *Phys. Rev. B* **71**, 035206 (2005)
678. J.M. Vail, D. Schindel, A. Yang, O. Penner, R. Pandey, S.H. Jiang, M. Blanco, A. Costales, *J. Phys. C Condens. Matter* **16**, 3371 (2004)
679. A. Gulans, R.A. Evarestov, I. Tale, *Phys. Stat. Sol. (c)* **2**, 507 (2005)
680. C. Sousa, Coen de Graaf, F. Illas, *Phys. Rev. B* **62**, 10013 (2000)
681. R.A. Evarestov, A.R. Sokolov, A.V. Leko, V.A. Veryazov, *J. Phys. Condens. Matter* **1**, 6611 (1989)
682. B.T. Plachenov, A.R. Sokolov, R.A. Evarestov, *Fiz. Tverdogo Tela* **28**, 867 (1986)
683. A.V. Bandura, R.A. Evarestov, *Phys. Stat. Sol. (b)* **64**, 635 (1974)
684. O. Daniliv, L. Kantorovich, *J. Phys. C Condens. Matter* **16**, 7233 (2004)
685. C. Pisani, F. Cora, R. Nada, S. Casassa, *Comp. Phys. Commun.* **82**, 139 (1994)
686. C. Pisani, U. Birkenheuer, *Comp. Phys. Commun.* **96**, 221 (1996)

687. C. Pisani, U. Birkenheuer, C. Casassa, F. Cora, EMBED01 User's Manual (University of Torino, Torino, 1999)
688. V. Sulimov, S. Casassa, C. Pisani, J. Garapon, B. Poumelle, *Model. Simul. Mater. Sci. Eng.* **8**, 763 (2000)
689. E. Scorza, U. Birkenheuer, C. Pisani, *J. Chem. Phys.* **107**, 9645 (1997)
690. C. Pisani, F. Cora, R. Dovesi, R. Orlando, *J. Elect. Spectrosc. Relat. Phenom.* **69**, 1 (1994)
691. T. Brudevoll, E.A. Kotomin, N.E. Christensen, *Phys. Rev. B* **53**, 7731 (1996)
692. Y.N. Hu, Z.Q. Gu, X.F. Zhong, W.Y. Ching, *Phys. Rev. B* **56**, 7277 (1997)
693. A. Stashans, E. Kotomin, J.L. Calais, *Phys. Rev. B* **49**, 14854 (1994)
694. I. Tanaka, K. Tatsumi, M. Nakano, H. Adachi, *J. Am. Ceram. Soc.* **85**, 68 (2002)
695. K. Matsunaga, T. Tanaka, T. Yamamoto, Y. Ikuhara, *Phys. Rev. B* **68**, 085110 (2003)
696. F. Janetzko, R.A. Evarestov, T. Bredow, K. Jug, *Phys. Stat. Sol. (b)* **241**, 1032 (2004)
697. F. Janetzko, T. Bredow, K. Jug, *J. Chem. Phys.* **116**, 8994 (2002)
698. M. Catti, G. Valerio, R. Dovesi, M. Causa, *Phys. Rev. B* **49**, 14179 (1994)
699. W. Choi, A. Termin, M.R. Hoffmann, *J. Phys. Chem.* **98**, 13669 (1994)
700. D. Morris, R. Dixon, F.H. Jones, Y. Dou, R. Egdell, S.W. Downes, G. Beamson, *Phys. Rev. B* **55**, 16083 (1997)
701. T. Umabayashi, T. Yamaki, H. Itoh, K. Asai, *J. Phys. Chem. Solids* **63**, 1909 (2002)
702. L.A. Errico, G. Fabricius, M. Renteria, *Z. Naturforsch.* **55**, 267 (2000)
703. A. Stashans, S. Llunell, R. Bergstrom, A. Hagfeldt, S. Lundquist, *Phys. Rev. B* **53**, 159 (1996)
704. A. Stashans, S. Llunell, R.W. Grimes, *J. Phys. Chem. Solids* **57**, 1293 (1996)
705. R.I. Eglitis, E.A. Kotomin, G. Borstel, *Defects Diffus. Forum* **226–228**, 169 (2004), online at <http://www.scientific.net>
706. H. Donnerberg, A. Birkholz, *J. Phys. Condens. Matter* **12**, 8239 (2000)
707. H. Moriwake, *Int. J. Quant. Chem.* **99**, 824 (2004)
708. A. Shigemi, T. Wada, *Jpn. J. Appl. Phys.* **43B**, 6793 (2004)
709. J.P. Buban, H. Iddir, S. Ogut, *Phys. Rev. B* **69**, R180102 (2004)
710. S.A. Prosandeyev, A.V. Fisenko, A.I. Riabchinski, I.A. Osipenko, I.P. Raevski, N. Safontsera, *J. Phys. Condens. Matter* **8**, 6705 (1996)
711. J. Robertson, *J. Appl. Phys.* **93**, 1054 (2003)
712. T. Tanaka, K. Matsunaga, Y. Ikuhara, T. Yamamoto, *Phys. Rev. B* **68**, 205213 (2003)
713. J. Carrasco, F. Illas, N. Lopez, E.A. Kotomin, Yu.F. Zhukovskii, S. Piskunov, J. Maier, K. Hermansson, *Phys. Stat. Sol. (c)* **2**, 153 (2005)
714. D. Ricci, G. Bano, G. Pacchioni, F. Illas, *Phys. Rev. B* **68**, 224105 (2003)
715. R.A. Evarestov, E.A. Kotomin, Yu.F. Zhukovskii, *Int. J. Quant. Chem.* **106**, 2173 (2006)
716. P.A. Cox, *Transition Metal Oxides* (Clarendon Press, Oxford 1995)
717. R. Astala, P.D. Bristowe, *Simul. Mater. Sci. Eng.* **9**, 415 (2001)
718. K. Szot, W. Speier, R. Carius, U. Zastrow, W. Beyer, *Phys. Rev. Lett.* **88**, 075508 (2002)
719. D.E. Usvyat, R.A. Evarestov, V.P. Smirnov, *Int. J. Quant. Chem.* **100**, 352 (2004)
720. R. Moos, K.H. Saerdtl, *J. Am. Ceram. Soc.* **80**, 2549 (1997)
721. D. Ricci, G. Bano, G. Pacchioni, F. Illas, *Phys. Rev. B* **68**, 224105 (2003)
722. J. Crawford, P.W.M. Jacobs, *Solid State Chem.* **144**, 423 (1999)
723. G. Kresse, J. Hafner, *VASP Guide* (University of Vienna, Austria, 2003)
724. M.G. Brik, *J. Phys. Chem. Solids* **67**, 856 (2006)
725. F.M. Michel-Calendini, K.A. Muller, *Solid State Commun.* **40**, 255 (1981)
726. M.O. Selme, P. Pecheur, G. Toussaint, *J. Phys. C Solid State Phys.* **17**, 5185 (1984)
727. H. Donnerberg, *Phys. Rev. B* **50**, 9053 (1994)
728. A.V. Postnikov, A.I. Poteryaev, G. Borstel, *Ferroelectrics* **206–207**, 69 (1998)
729. R.I. Eglitis, A.V. Postnikov, G. Borstel, *Phys. Stat. Sol. (b)* **209**, 187 (1998)
730. I.I. Tupitsyn, A. Deineka, V.A. Trepakov, L. Jastrabik, S.E. Kapphan, *Phys. Rev. B* **64**, 195111 (2001)
731. R.K. Astala, P.D. Bristowe, *Model. Simul. Mater. Sci. Eng.* **12**, 79 (2004)
732. R. Waser, T. Bieger, J. Maier, *Solid State Commun.* **76**, 1077 (1990)

733. J. Fleig, K.D. Kreuer, J. Maier, *Handbook of Advanced Ceramics* (Elsevier, Singapore, 2003), p. 57
734. G. Banach, W.M. Temmerman, Phys. Rev. B **69**, 054427 (2004)
735. H. Zenia, G.A. Gehring, G. Banach, W.M. Temmerman, Phys. Rev. B **71**, 024416 (2005)
736. J. Geck, P. Wochner, D. Bruns, B. Buchner, U. Gebhardt, S. Kiele, P. Reutler, A. Revcolevschi, Phys. Rev. B **69**, 104413 (2004)
737. D. Fuks, L. Bakaleinikov, E.A. Kotomin, J. Felsteiner, A. Gordon, R.A. Evarestov, D. Gryaznov, J. Maier, Solid State Ion. **177**, 217 (2006)
738. J.K. Perry, J. Tahir-Kheli, W.A. Goddard III, Phys. Rev. B **63**, 144510 (2001)
739. D. Fuks, S. Dorfman, S. Piskunov, E.A. Kotomin, Phys. Rev. B **71**, 014111 (2005)
740. D. Fuks, S. Dorfman, E.A. Kotomin, Yu. Zhukovskii, A.M. Stoneham, Phys. Rev. Lett. **85**, 4333 (2000)
741. D. Fuks, S. Dorfman, J. Felsteiner, L. Bakaleinikov, A. Gordon, E.A. Kotomin, Solid State Ion. **173**, 107 (2004)
742. L. Rormark, S. Stolen, K. Wik, T. Grande, J. Solid State Chem. **163**, 186 (2002)
743. A.G. Kchachaturyan, *Theory of Structural Transformations in Solids* (Wiley, New York, 1983)
744. *International Tables for Crystallography, volume E, Subperiodic Groups*, ed. by V. Kopsky, D.B. Litvin (Kluwer Academic, Dodrecht/Boston/London, 2002)
745. V. Kopsky, Acta Cryst. A **45**, 805–816 (1989)
746. V. Kopsky, Acta Cryst. A **56**, 370 (2000)
747. E.A. Wood, Bell Telephone Tech. J. **43**, 541 (1964)
748. V.P. Smirnov, P. Tronc, Phys. Solid State **48**, 1295 (2006)
749. C. Noguera, *Physics and Chemistry at Oxide Surfaces* (Cambridge University Press, Cambridge, 1996)
750. C. Noguera, J. Phys. Condens. Matter **12**, R367 (2000)
751. F. Finocchi, F. Bottin, C. Noguera, in *Computational Materials Science*, ed. by C.R.A. Catlow, E.A. Kotomin (IOS press Amsterdam, 2003), p. 196
752. T. Bredow, G. Geudtner, K. Jug, J. Chem. Phys. **105**, 6395 (1996)
753. R.A. Evarestov, T. Bredow, K. Jug, Phys. Solid State **43**, 1774 (2001)
754. T. Bredow, K. Jug, Chem. Phys. Lett. **223**, 89 (1994)
755. P.W. Tasker, J. Phys. C Solid State Phys. **12** (1979)
756. J.C. Boettger, Phys. Rev. B **49**, 16798 (1994)
757. V. Fiorentini, M.J. Methfesse, J. Phys. Condens. Matter **8**, 6525 (1996)
758. L. Fu, E. Yaschenko, L. Resta, Phys. Rev. B **60**, 2697 (1999)
759. R.A. Evarestov, A.V. Bandura, Int. J. Quant. Chem. **100**, 452 (2004)
760. R.A. Evarestov, A.V. Bandura, Int. J. Quant. Chem. **96**, 282 (2002)
761. L.N. Kantorovich, M.J. Gilan, Surf. Sci. **374**, 373 (1997)
762. P. Reinhardt, B. Hess, Phys. Rev. B **50**, 12015 (1994)
763. R.A. Evarestov, V.P. Smirnov, D.E. Usvyat, Int. J. Quant. Chem. **104**, 102 (2005)
764. G. Fernandes-Cata, L.G. Alvarez, R. Dovesi, C.M. Zicovich-Wilson, J. Phys. Chem. B **106**, 7316 (2004)
765. S.P. Bates, G. Kresse, M.G. Gillan, Surf. Sci. **385**, 386 (1997)
766. U. Diebold, Surf. Sci. Rep. **48**, 53 (2003)
767. M. Calatayud, B. Mguig, C. Minot, Surf. Sci. **526**, 297 (2003)
768. M. Calatayud, A. Markovits, M. Menetrey, B. Mguig, C. Minot, Catal. Today **85**, 125 (2003)
769. M. Menetrey, A. Markovits, C. Minot, G. Pacchioni, J. Phys. Chem. B **108**, 12858 (2004)
770. C. Noguera, F. Finocchi, J. Goniakowski, J. Phys. Condens. Matter **16**, S2509 (2004)
771. T. Bredow, L. Giordano, F. Cinquini, G. Pacchioni, Phys. Rev. B **70**, 035419 (2004)
772. M. Calatayud, C. Minot, Surf. Sci. **552**, 169 (2004)
773. A.V. Bandura, D.G. Sykes, V. Shapovalov, T.N. Truong, J.D. Kubicki, R.A. Evarestov, J. Phys. Chem. B **108**, 7844 (2004)
774. A.V. Bandura, J.O. Sofo, J.D. Kubicki, J. Phys. Chem. B **110**, 8386 (2006)
775. S.J. Thompson, S.P. Lewis, Phys. Rev. B **73**, 073403 (2006)

776. K.J. Hameeuw, G. Cantele, D. Ninno, F. Trani, G. Iadonisi, *J. Chem. Phys.* **124**, 024708 (2006)
777. M.L. Sushko, A.Yu. Gal, A.L. Shluger, *J. Phys. Chem. B* **110**, 4853 (2006)
778. G.U. von Oertzen, A.R. Gerson, *Int. J. Quant. Chem.* **106**, 2054 (2006)
779. P. Persson, A. Stashans, R. Bergstrom, S. Lunell, *Int. J. Quant. Chem.* **70**, 1055 (1998)
780. K. Jug, G. Geudtner, *J. Mol. Cat. A* **119**, 143 (1997)
781. T. Brinkley, M. Dietrich, T. Engel, P. Farral, G. Gantner, A. Schafer, A. Szuchmacher, *Surf. Sci.* **395**, 292 (1998)
782. N.M. Harrison, X.G. Wang, J. Muskat, M. Scheffer, *Faraday Discuss.* **114**, 305 (1999)
783. J. Leconte, A. Markovits, M.K. Skalli, C. Minot, A. Belmajdoub, *Surf. Sci.* **497**, 194 (2002)
784. E.V. Stefanovich, T.N. Truong, *J. Phys. Chem. B* **102**, 3018 (1998)
785. J. Goniakowski, M.J. Lindan, *Surf. Sci.* **350**, 145 (1996)
786. P.J.D. Lindan, N.M. Harrison, J.M. Holender, M.J. Gillan, *Phys. Rev. Lett.* **80**, 762 (1998)
787. G. Charlton, P.B. Howes, C.L. Nickin, P. Steadman, J.S.G. Taylor, C.A. Muryn, S.P. Harte, J. Mercer, R. McGrath, D. Norman, T.S. Turner, G. Thornton, *Phys. Rev. Lett.* **78**, 495 (1997)
788. E.V. Stefanovich, T.N. Truong, *Chem. Phys. Lett.* **299**, 623 (1999)
789. T.T. Rantala, T.S. Rantala, V. Lantto, *Surf. Sci.* **420**, 103 (1999)
790. J. Oviedo, M.J. Gillan, *Surf. Sci.* **463**, 93 (2000)
791. I. Manassidis, J. Goniakowski, L.N. Kantorovich, M.J. Gillan, *Surf. Sci.* **339**, 258 (1995)
792. J. Goniakowski, M.J. Gillan, *Surf. Sci.* **350**, 145 (1996)
793. S.P. Bates, *Surf. Sci.* **512**, 29 (2002)
794. P.J.D. Lindan, *Chem. Phys. Lett.* **328**, 325 (2000)
795. M. Calatayud, J. Andrus, A. Beltrn, *Surf. Sci.* **430**, 213 (1999)
796. F. Ciriaco, L. Cassidei, M. Cacciatore, G. Petrella, *Chem. Phys.* **303**, 55 (2004)
797. M. Melle-Franco, G. Pacchioni, *Surf. Sci.* **461**, 54 (2000)
798. F.R. Sensato, R. Custdio, M. Calatayud, A. Beltron, J. Andrus, J.R. Sambrano, E. Longo, *Surf. Sci.* **511**, 408 (2002)
799. R.A. Evarestov, A.V. Bandura, E.V. Proskurov, *Phys. Stat. Sol. (b)* **243**, 1823 (2006)
800. A.V. Postnikov, P. Entel, P. Ordejon, *Phase Trans.* **75**, 143 (2002)
801. Y. Yamaguchi, K. Tabata, T. Yashima, *J. Mol. Struct. (Theochem)* **714**, 221 (2005)
802. H. Szuber, G. Czempik, R. Larciprete, B. Adamowicz, *Sens. Actuators B Chem.* **70**, 177 (2000)
803. J.M. Themlin, R. Sporken, J. Darville, R. Caudano, J.M. Gilles, R.L. Johnson, *Phys. Rev. B* **42**, 11914 (1990)
804. A.L. Dawar, J.C. Joshi, *J. Mater. Sci.* **19**, 1 (1984)
805. V.A. Gercher, D.F. Cox, *Surf. Sci.* **322**, 177 (1995)
806. T. Hiemstra, H. Yong, W.H. van Riemsdijk, *Langmuir* **15**, 5942 (1999)
807. S. Piskunov, E.A. Kotomin, E. Heifets, J. Maier, R.I. Eglitis, G. Borstel, *Surf. Sci.* **575**, 75 (2005)
808. R.A. Evarestov, A.V. Bandura, V.E. Alexandrov, *Phys. Stat. Sol. (b)* **246**, 1013 (2006)
809. N. Erdman, K.R. Poeppelmeier, M. Asta, O. Warschkow, D.E. Ellis, L.D. Marks, *Nature* **419**, 55 (2002)
810. A. Ikeda, T. Nishimura, T. Morishita, Y. Kido, *Surf. Sci.* **433–435**, 520 (1999)
811. G. Charlton, S. Brennan, C.A. Muryn, R. McGrath, D. Norman, T.S. Turner, G. Thornton, *Surf. Sci.* **457**, L376 (2000)
812. J. Padilla, D. Vanderbilt, *Surf. Sci.* **418**, 64 (1998)
813. N.V. Krainyukova, V.V. Butskii, *Surf. Sci.* **454**, 628 (2000)
814. E. Heifets, R.I. Eglitis, E.A. Kotomin, J. Maier, G. Borstel, *Phys. Rev. B* **64**, 235417 (2001)
815. E. Heifets, R.I. Eglitis, E.A. Kotomin, J. Maier, G. Borstel, *Surf. Sci.* **513**, 211 (2002)
816. A. Asthagiri, D.S. Sholl, *Phys. Rev. B* **73**, 125432 (2006)
817. K. van Benthem, C. Elsässer, *J. Appl. Phys.* **90**, 6156 (2001)
818. Y.S. Lee, J.S. Lee, T.W. Noh, D.Y. Byun, K.S. Yoo, K. Yamaura, E.T. Muromachi, *Phys. Rev. B* **67**, 113101 (2003)
819. Z.Q. Li, J.L. Zhu, C.Q. Wu, Z. Tang, Y. Kawazoe, *Phys. Rev. B* **58**, 8075 (1998)

820. S. Kimura, J. Yamauchi, M. Tsukada, S. Watanabe, Phys. Rev. B **51**, 11049 (1995)
821. Yu.F. Zhukovskii, S. Piskunov, E.A. Kotomin, O. Sychev, G. Borstel, Microelectr. Eng. **81**, 467 (2005)
822. S. Piskunov, E.A. Kotomin, E. Heifets, Microelectr. Eng. **81**, 472 (2005)
823. S. de Lazaro, E. Longo, J.R. Sambrano, A. Bertran, Surf. Sci. **552**, 149 (2004)
824. X.Y. Hue, C.L. Wang, W.L. Zhong, Surf. Sci. **550**, 73 (2004)
825. G. Borstel, R.I. Eglitis, E.A. Kotomin, E. Heifets, Phys. Stat. Sol. (b) **236**, 253 (2003)
826. N. Erdman, L.D. Marks, Surf. Sci. **526**, 107 (2003)
827. R. Bader, *Atoms in Molecules: A Quantum Theory* (Oxford University Press, New York, 1990)
828. A. Asthagiri, D.S. Sholl, J. Chem. Phys. **116**, 9914 (2002)
829. A. Stashans, F. Erazo, J. Ortiz, P. Valverde, Philos. Mag. B **81**, 1977 (2001)
830. Z. Fang, K. Terakura, Surf. Sci. **470**, L75 (2000)
831. J. Carrasco, F. Illas, N. Lopez, E.A. Kotomin, Yu.F. Zhukovskii, R.A. Evarestov, Yu.A. Mastrikov, S. Piskunov, J. Maier, Phys. Rev. B **73**, 064106 (2006)
832. J. Carrasco, J.R.B. Gomes, F. Illas, Phys. Rev. B **69**, 064116 (2004)
833. P. Mori-Sanchez, J.M. Recio, B. Silvi, C. Sousa, A.M. Pendas, V. Luana, F. Illas, Phys. Rev. B **66**, 075103 (2002)
834. R.A. Evarestov, E.A. Kotomin, E. Heifets, J. Maier, G. Borstel, Solid State Commun. **127**, 367 (2003)
835. R.A. Evarestov, E.A. Kotomin, D. Fuks, J. Felsteiner, J. Maier, Appl. Surf. Sci. **238**, 457 (2004)
836. E. Heifets, E.A. Kotomin, J. Maier, Phys. Chem. Chem. Phys. **5**, 4180 (2003)
837. F. Bottin, F. Finocchi, C. Noguera, Phys. Rev. B **68**, 035418 (2003)
838. R.A. Evarestov, E.A. Kotomin, Yu.A. Mastrikov, D. Gryaznov, E. Heifets, J. Maier, Phys. Rev. B **72**, 214411 (2005)
839. J.V. Vondele, M. Crack, F. Mohamed, M. Parrinello, T. Chassaing, J. Hutter, Comp. Phys. Commun. **167**, 103 (2005)
840. C. Pisani, J. Mol. Struct. (Theochem) **463**, 125 (1999)
841. R. Orlando, R. Dovesi, P. Ugliengo, C. Roetti, V.R. Saunders, Int. J. Inorg. Mater. **1**, 147 (1999)
842. R. Dovesi, R. Orlando, C. Roetti, C. Pisani, V.R. Saunders, Phys. Stat. Sol. (b) **217**, 63 (2000)
843. C. Pisani, R. Dovesi, C. Roetti, M. Causa, R. Orlando, S. Casassa, V.R. Saunders, Int. J. Quant. Chem. **77**, 1032 (2000)
844. G. Te Velde, F.M. Bickelhaupt, E.J. Baerends, C.F. Guerra, S.J.A. VAN Gisbergen, J.G. Snijders, T. Ziegler, J. Comput. Chem. **22**, 931 (2001)
845. A.E. Mattson, P.A. Schultz, M.P. Desjarlais, T.R. Mattsson, K. Leung, Model. Simul. Mater. Sci. Eng. **13**, R1 (2005)
846. B. Delley, J. Chem. Phys. **113**, 7756 (2000)
847. H. Eschrig, K. Koepernik, I. Chaplygin, J. Solid State Chem. **176**, 482 (2003)
848. S.D. Kenny, A.P. Horsfield, H. Fujitani, Phys. Rev. B **62**, 4899 (2000)
849. R.A. Evarestov, I.I. Tupitsyn, V.A. Veryazov, Int. J. Quant. Chem. **52**, 295 (2004)
850. J.J.P. Stewart, J. Mol. Mod. **10**, 155 (2004)
851. L. Kantorovich, A. Stashans, E. Kotomin, P.W.M. Jacobs, Int. J. Quant. Chem. **52**, 1177 (1994)
852. B. Civalieri, F. Napoli, Y. Noel, C. Roetti, R. Dovesi, Cryst. Eng. Commun. **8**, 364 (2006), see online www.rsc.org/crystengcomm
853. A. Kokalj, Comput. Mater. Sci. **28**, 155 (2003)
854. J.F. Scott, *Ferroelectric Memories* (Springer, Berlin, 2000)
855. R. Waser, *Nanoelectronics and Information Technology: Advanced Electronic Materials and Novel Devices* (Wiley-VCH, Weinheim, 2003)
856. K.D. Kreuer, Rev. Mater. Res. **33**, 333 (2003)
857. H. Iwahara, Y. Asakura, K. Katahira, M. Tanaka, Solid State Ion, **168**, 299 (2004)
858. R. Mitchell, *Perovskites Modern and Ancient* (Almaz, Ontario, 2002)

859. P. Goudochnikov, A.J. Bell, *J. Phys. Condens. Matter* **19**, 176201 (2007)
860. R.P. Stoffel, C. Wessel, M.W. Lumeij, R. Dronskowski, *Angew. Chem. Int. Ed.* **49**, 5242 (2010)
861. W. Zhong, D. Vanderbilt, K.M. Rabe, *Phys Rev B* **52**, 6301(1995)
862. J. Iniguez, D. Vanderbilt, *Phys. Rev. Lett.* **89**, 115503 (2002)
863. T. Nishimatsu, M. Iwamoto, Y. Kawazoe, U.V. Waghmare, *Phys. Rev. B* **82**, 134106 (2010)
864. S. Tinte, J. Iniguez, K.M. Rabe, D. Vanderbilt, *Phys. Rev. B* **58**, 11959 (1998)
865. Ph. Ghosez, E. Cockayne, U.V. Waghmare, K.M. Rabe, *Phys. Rev. B* **60**, 836 (1999)
866. Y. Hie, H. Yu, G. Zhang, H. Fu, *J. Phys. Condens. Matter* **20**, 215215 (2008)
867. R. Wahl, D. Vogtenhuber, G. Kresse, *Phys. Rev. B* **78**, 104116 (2008)
868. A.V. Bandura, R.A. Evarestov, D.D. Kuruch, *Surf. Sci.* **604**, 1591 (2010)
869. A. Bilic, J.D. Gale, *Phys. Rev. B* **79**, 174107 (2009)
870. A.R. Akbarzadeh, I. Kornev, C. Malibert, L. Bellaiche, J.M. Kiat, *Phys. Rev. B* **72**, 205104 (2005)
871. J.W. Bennett, I. Grinberg, A.M. Rappe, *Phys. Rev. B* **73**, 180102(R) (2006)
872. P.G. Sundell, M.E. Bjorketun, G. Wahnstrom, *Phys. Rev. B* **73**, 104112 (2006)
873. M.E. Bjorketun, P.G. Sundell, G. Wahnstrom, *FaradayDiscuss.* **134**, 247 (2007)
874. R. Vali, *Solid State Commun.* **147**, 1 (2008)
875. A. Bouhemadu, F. Djabi, R. Khenata, *Phys. Lett. A* **372**, 4257 (2008)
876. H. Zhao, A. Chong, Y. Wang, *Phys. B* **404**, 2192 (2009)
877. Q.-J. Liu, Z.-T. Liu, L. Feng, H. Tian, *Phys. B* **405**, 4032 (2010)
878. I.D. Prodan, G.E. Scuseria, R.L. Martin, *Phys. Rev. B* **76**, 033101 (2007)
879. E. Heifets, E. Kotomin, V.A. Trepakov, *J. Phys. Condens. Matter* **18**, 4845 (2006)
880. D.I. Bilc, R. Orlando, R. Shaltar, G.M. Rignanese, J. Iniguez, Ph. Ghosez, *Phys. Rev. B* **77**, 165107 (2008)
881. Z. Wu, R.E. Cohen, *Phys. Rev. B* **73**, 235116 (2006)
882. R.A. Evarestov, *Phys. Rev. B* **83**, 014105 (2011)
883. R.A. Evarestov, A.V. Bandura, *J. Comput. Chem.* (2012)
884. M.M. Hurley, L.F. Pacios, P.A. Christiansen, R.B. Ross, W.C. Ermler, *J. Chem. Phys.* **84**, 6840 (1986)
885. P.J. Hay, W.R. Wadt, *J. Chem. Phys.* **82**, 270–299 (1984)
886. M. Ferrero, M. Rerat, B. Kirtman, R. Dovesi, *J. Chem. Phys.* **129**, 244110 (2008)
887. M. Ferrero, M. Rerat, R. Orlando, R. Dovesi, *J. Comput. Chem.* **29**, 1450 (2008)
888. K. Kunc, R. Martin, *Phys. Rev. Lett.* **48**, 406 (1982)
889. R.A. Evarestov, M.V. Losev, *J. Comput. Chem.* **30**, 2645 (2009)
890. J.D. Axe, *Phys. Rev.* **157**, 429 (1967)
891. M. Uludogan, D.P. Guarin, Z.E. Gomez, T. Cagin, W.A. Goddard III, *Comp. Mod. Eng. Sci.* **24**, 215 (2008)
892. H.T. Stokes, E.H. Kisi, D.M. Hatch, C.J. Howard, *Acta. Cryst. B* **58**, 934 (2002)
893. Ph. Ghosez, X. Gonze, J.-P. Michenaud, *Ferroelectrics* **194**, 39 (1997)
894. Ph. Ghosez, X. Gonze, J.-P. Michenaud, *Ferroelectrics* **220**, 1 (1999)
895. P. Hermet, M. Veithen, Ph. Ghosez, *J. Phys. Condens. Matter* **21**, 215901 (2009)
896. S. Sanna, C. Thierfelder, S. Wippermann, T.P. Sinha, W.G. Schmidt, *Phys. Rev. B* **83**, 054112 (2011)
897. X.Y. Deng, H.T. Zhang, T. Li, D.J. Li, J.B. Li, X.H. Wang, I.T. Li, *Chinese Sci. Bull.* **55**, 2182 (2010)
898. U.D. Venkateswaran, V.M. Naik, R. Naik, *Phys. Rev. B* **58**, 14256 (1998)
899. Z. Lazarevic, N. Romcevic, M. Vijatovic, N. Paunovic, M. Romcevic, B. Stojanovic, Z. Dohcevic-Mitrovic, *Acta Phys. Polonica A* **115**, 808 (2009)
900. K. Labidi, M. Fontana, B. Jannot, *Solid State Commun.* **76**, 765 (1990)
901. B. Wang, C. Sun, *Appl. Opt.* **40**, 672 (2001)
902. X. Wu, D. Vanderbilt, D.R. Hamann, *Phys. Rev. B* **72**, 035105 (2005)
903. E. Choudhury, J. Walter, A.I. Kolesnikov, C.-K. Loong, *Phys. Rev. B* **77**, 134111 (2008)
904. K. Rabe, P. Ghosez, *Top Appl. Phys.* **105**, 117 (2007)

905. M.A. Blanco, E. Francisco, V. Luaza, *Comput. Phys. Commun.* **158**, 57 (2004)
906. N. Iles, A. Kellou, K. Driss-Khodja, B. Amrani, F. Lemoigno, D. Bourbie, H. Aourag, *Comp. Mater. Sci.* **39**, 896 (2007)
907. Z. Huang, J. Feng, W. Pan, *Comput. Mater. Sci.* **50**, 3056 (2011)
908. A. Boudali, M.D. Khodja, B. Amrani, D. Bourbie, K. Amara, A. Abada, *Phys. Lett. A* **373**, 879 (2009)
909. S. Baroni, P. Giannozzi, E. Isaev, *Rev. Mineral. Geochem.* **71**, 39 (2010)
910. B.B. Karki, R.M. Wentzcovitch, S. de Gironcoli, S. Baroni, *Phys. Rev. B* **62**, 14750 (2000)
911. Y.G. Yu, R.M. Wentzcovitch, V.L. Vinograd, R.J. Angel, *J. Geophys. Res.* **116**, B02208 (2011)
912. S. Stolen, R.G. Trunnes, *Phys. Earth Planet. Interiors* **164**, 50 (2007)
913. A.V. Bandura, R.A. Evarestov, *J. Comput. Chem.* (2012)
914. R.D. King-Smith, D. Vanderbilt, *Phys. Rev. B* **49**, 5828 (1994)
915. N.D. Drummond, G.J. Ackland, *Phys. Rev. B* **65**, 184104 (2002)
916. G.H. Kwei, A.C. Lawson, S.J.L. Billinge, *J. Phys. Chem.* **97**, 2368 (1993)
917. A. Schaefer, H. Schmitt, A. Dorr, *Ferroelectrics* **69**, 253 (1986)
918. M. Zgonik, P. Bernasconi, M. Duelli, R. Schlessler, P. Gunter, M.H. Garrett, D. Rytz, Y. Zhu, X. Wu, *Phys. Rev. B* **50**, 5941 (1994)
919. J.W. Edwards, R. Speiser, H.L. Johnston, *J. Am. Chem. Soc.* **73**, 2934 (1951)
920. K.H. Hellwege, A.M. Hellwege (eds.), *Ferroelectrics and Related Substances; Landolt-Bornstein, New Series, Group III*, vol. 16 (Springer, Berlin, 1981)
921. S.H. Wemple, *Phys. Rev. B* **2**, 2679 (1970)
922. G. Burns, F.H. Dacol, *Solid State Commun.* **42**, 9 (1982)
923. T. Nakamura, *Ferroelectrics* **137**, 65 (1992)
924. D.A. Tenne, X.X. Xi, Y.L. Li, L.Q. Chen, A. Soukiassian, M.H. Zhu, A.R. James, J. Lettieri, D.G. Schlom, W. Tian, X.Q. Pan, *Phys. Rev.* **69**, 174101 (2004)
925. F. Birch, *Phys. Rev.* **71**, 809 (1947)
926. O.L. Anderson, *Equations of State of Solids for Geophysics and Ceramic Science* (Oxford University Press, Oxford, 1995)
927. D.C. Wallace, *Thermodynamics of Crystals* (Dover, New York, 1998)
928. M.V.R. Rao, A.M. Umarji, *Bull. Mater. Sci.* **20**, 1023 (1997)
929. J.R.G. Keyston, J.D. Macpherson, E.W. Guptill, *Rev. Sci. Instrum.* **30**, 246 (1959)
930. G. Shirane, A. Takeda, *J. Phys. Soc. Jpn.* **6**, 128 (1951)
931. N.A. Masyukov, A.V. Dmitriev, *Bull. Russ. Acad. Sci. Phys.* **71**, 1076 (2007)
932. S.S. Todd, R.E. Lorensen, *J. Am. Chem. Soc.* **74**, 2043 (1952)
933. J.J. Rehr, R.C. Albers, *Rev. Mod. Phys.* **72**, 621 (2000)
934. B. Ravel, *J. Alloy Comp.* **401**, 118 (2005)
935. M. Benfatto, C.R. Natoli, A. Filippini, *Phys. Rev. B* **40**, 9626 (1989)
936. A. Filippini, A. Di Cicco, C.R. Natoli, *Phys. Rev. B* **52**, 15122 (1995)
937. A.L. Ankudinov, B. Ravel, J.J. Rehr, S.D. Conradson, *Phys. Rev. B* **58**, 7565 (1998)
938. N. Dimakis, G. Bunker, *Phys. Rev. B* **58**, 2467 (1998)
939. A.A. Poiarkova, J.J. Rehr, *Phys. Rev. B* **59**, 948 (1999)
940. A. Filippini, A. Di Cicco, *Phys. Rev. B* **52**, 15135 (1995)
941. M. Winterer, *J. Appl. Phys.* **88**, 5635 (2000)
942. R.L. McGreevy, *J. Phys. Condens. Matter* **13**, R877 (2001)
943. P.J. Merkling, A. Muñoz-Páez, R.R. Pappalardo, M.E. Sánchez, *Phys. Rev. B* **64**, 092201 (2001)
944. D. Cabaret, M. Le Grand, A. Ramos, A.M. Flank, S. Rossano, L. Galois, G. Calas, D. Ghaleb, *J. Non-Cryst. Solids* **289**, 1 (2001)
945. Y. Okamoto, *Nucl. Instrum. Meth. Phys. Res. A* **526**, 572 (2004)
946. F. Farges, Y. Lefrère, S. Rossano, A. Berthereau, G. Calas, G.E. Brown Jr., *J. Non-Cryst. Solids* **344**, 176 (2004)
947. A. Di Cicco, A. Trapananti, *J. Phys. Condens. Matter* **17**, S135 (2005)
948. G. Ferlat, J.C. Soetens, A. SanMiguel, P.A. Bopp, *J. Phys. Condens. Matter* **17**, S145 (2005)

949. A. Kuzmin, R.A. Evarestov, J. Phys. Condens. Matter **21**, 055401 (2009)
950. A. Kalinko, R.A. evarestov, A. Kuzmin, J. Purans, J. Phys. Conf. Ser. **190**, 012080 (2009)
951. A. Kuzmin, R.A. Evarestov, J. Phys. Conf. Ser. **190**, 012024 (2009)
952. M. Vračar, A. Kuzmin, R. Merkle, J. Purans, E.A. Kotomin, J. Maier, O. Mathon, Phys. Rev. B **76**, 174107 (2007)
953. R. Dovesi, V.R. Saunders, C. Roetti, R. Orlando, C.M. Zicovich-Wilson, F. Pascale, B. Civalieri, K. Doll, N.M. Harrison, I.J. Bush, P. D'Arco, M. Llunell, CRYSTAL09 User's Manual (University of Torino, Torino, 2010)
954. G. Kresse, J. Furthmuller, VASP the Guide (Universität Wien, Wien, 2007)
955. J.D. Gale, Philos. Mag. B **73**, 3 (1996)
956. G.D. Gale, A.L. Rohl, Mol. Simul. **9**, 291 (2003)
957. A. Kuzmin, Phys. B **208&209**, 175 (1995)
958. V.E. Alexandrov, J. Maier, R.A. Evarestov, Phys. Rev. B **77**, 075111 (2008)
959. B.S. Thomas, N.A. Marks, B.D. Begg, Nucl. Instrum. Meth. Phys. Res. B **228**, 288 (2005)
960. G.M. Meyer, R.J. Nemes, J. Hutton, Ferroelectrics **21**, 461 (1978)
961. S.A. Howard, J.K. Yau, H.U. Anderson, J. Appl. Phys. **65**, 1492 (1989)
962. P.P. Ewald, Ann. Phys. **64**, 253 (1921)
963. M. Fischer, A. Lahmar, M. Maglione, A. Sanmiguel, J.P. Itié, A. Polian, F. Baudelet, Phys. Rev. B **49**, 12451 (1994)
964. A. Kuzmin, J. Purans, M. Benfatto, C.R. Natoli, Phys. Rev. B **47**, 2480 (1993)
965. A. Kuzmin, J. Purans, J. Phys. Condens. Matter **5**, 9423 (1993)
966. A. Kuzmin, Latvian J. Phys. Tech. Sci. **2**, 7 (2006)
967. B. Houser, R. Ingalls, Phys. Rev. B **61**, 6515 (2000)
968. R.A. Evarestov, A. Kalinko, A. Kuzmin, M. Losev, J. Purans, Integr. Ferroelectrics **108**, 1 (2009)
969. T. Chatterji, P.F. Henry, R. Mittal, S.L. Chaplot, Phys. Rev. B **78**, 134105 (2008)
970. N.Tsuda, Y. Sumino, I. Ohno, T. Akahane, J. Phys. Soc. Jpn. **41**, 1153 (1976)
971. A. Kuzmin, J. Purans, M. Benfatto, C.R. Natoli, Phys. Rev. B **47**, 2480 (1993)
972. H. Wang, F.D. Medina, D.D. Liu, Y.D. Zhou, J. Phys. Condens. Matter **6**, 5373 (1994)
973. H. Kraus, V.B. Mikhailik, Y. Ramachers, D. Day, K.B. Hutton, J. Telfer, Phys. Lett. B **610**, 37 (2005)
974. H. Grassmann, H.G. Moser, E. Lorenz, J. Lumin. **33**, 21 (2005)
975. A.R. Phani, M. Passacantando, L. Lozzi, S. Santucci, J. Mater. Sci. **35**, 4879 (2000)
976. A. Kuzmin, R. Kalendarev, A. Kursitis, J. Purans, J. Non-Cryst. Solids **353**, 1840 (2007)
977. P.F. Schofield, K.S. Knight, G. Cressey, J. Mater. Sci. **31**, 2873 (1996)
978. H. Kraus, V.B. Mikhailik, L. Vasylichko, D. Day, K.B. Hutton, J. Telfer, Yu. Prots, Phys. Stat. Sol. (a) **204**, 730 (2007)
979. A. Kuzmin, J. Purans, Rad. Meas. **33**, 583 (2001)
980. Y. Liu, H. Wang, G. Chen, Y.D. Zhou, B.Y. Gu, B.Q. Hu, J. Appl. Phys. **64**, 4651 (1998)
981. H. Wang, F.D. Medina, Y.D. Zhou, N.Q. Zhang, Phys. Rev. B **45**, 10356 (1992)
982. V.N. Kolobanov, I.A. Kamenskikh, V.V. Mikhailin, I.N. Shpinkov, D.A. Spassky, B.I. Zadneprovsky, L.I. Potkin, G. Zimmerer, Nucl. Instrum. Methods Phys. Res. A **486**, 496 (2002)
983. L. Grigorjeva, D. Millers, S. Chernov, V. Pankratov, A. Watterich, Rad. Meas. **33**, 645 (2001)
984. V.B. Mikhailik, H. Kraus, G. Miller, M.S. Mykhaylyk, D. Wahl, J. Appl. Phys. **97**, 083523 (2005)
985. S.B. Mikhlin, A.N. Mishin, A.S. Potapov, P.A. Rodnyi, A.S. Voloshinovskii, Nucl. Instrum. Methods Phys. Res. A **486**, 295 (2002)
986. V. Nagirnyi, E. Feldbach, L. Jönsson, M. Kirm, A. Kotlov, A. Lushchik, V.A. Nefedov, B.I. Zadneprovski, Nucl. Instrum. Methods Phys. Res. A **486**, 395 (2002)
987. M. Itoh, N. Fujita, Y. Inabe, J. Phys. Soc. Jpn. **75**, 084705 (2006)
988. Yu.A. Hizhnyi, T.N. Nikolaenko, S.G. Nedilko, Phys. Stat. Sol. (c) **4**, 1217 (2007)
989. A. Kalinko, A. Kuzmin, R.A. Evarestov, Solid State Comm. **149**, 425 (2009)
990. R. Dovesi et al., *Crystal06. Users Manual* (University of Turin, Turin, 2006)

991. P.J. Hay, W.R. Wadt, J. Chem. Phys. **82** **270**, 284–299 (1985)
992. F. Cora, A. Patel, N.M. Harrison, R. Dovesi, C.R. Catlow, J. Am. Chem. Soc. **118**, 12174 (1996)
993. J.P. Perdew, *Electronic Structure of Solids* (Akademie Verlag, Berlin, 1991)
994. A. Kuzmin, A. Kalinko, R.A. Evarestov, Cent. Eur. J. Phys. **9**, 502 (2011)
995. F.J. Gil-Llambías, H. Rodriguez, I. Bouyssiers, M. Escudey, I. Carkovic, J. Catal. **102**, 37 (1986)
996. B. Scheffer, P. Molhoek, J.A. Moulijn, Appl. Catal. **46**, 11 (1989)
997. R.A. Diaz-Real, R.S. Mann, I.S. Sambhi, Ind. Eng. Chem. Res. **32**, 1354 (1993)
998. D.L. Stern, R.K. Grasselli, J. Catal. **167**, 570 (1997)
999. A.K. Bhattacharya, R.G. Biswas, A. Hartridge, J. Mater. Sci. **32**, 353 (1997)
1000. V. Dusastre, D.E. Williams, J. Mater. Chem. **9**, 965 (1999)
1001. R.C. Pullar, S. Farrah, N.McN. Alford, J. Eur. Ceram. Soc. **27**, 1059 (2007)
1002. T. Ejima, T. Banse, H. Takatsuka, Y. Kondo, M. Ishino, N. Kimura, M. Watanabe, I. Matsubara, J. Lumin. **119**, 59 (2006)
1003. P.S. Pandey, N.S. Bhav, R.B. Kharat, Electrochim. Acta **51**, 4659 (2006)
1004. A. Kuzmin, J. Purans, R. Kalendarev, D. Pailharey, Y. Mathey, Electrochim. Acta **46**, 2233 (2001)
1005. G.A. Niklasson, C.G. Granqvist, J. Mater. Chem. **17**, 127 (2007)
1006. S.K. Deb, Solar Energy Mater. Solar Cells **92**, 245 (2008)
1007. K. Bange, Solar Energy Mater. Solar Cells **58**, 1 (1999)
1008. S. Hüfner, Adv. Phys. **43**, 183 (1994)
1009. R.O. Keeling Jr., Acta Cryst. **10**, 209 (1957)
1010. C.P. Landee, E.F. Westrum Jr., J. Chem. Thermodyn. **8**, 471 (1976)
1011. O. Heyer, N. Hollmann, I. Klassen, S. Jodlauk, L. Bohaty, P. Becker, J.A. Mydosh, T. Lorenz, D. Khomskii, J. Phys. Condens. Matter **18**, L471 (2006)
1012. H. Weitzel, Z. Kristallogr. **144**, 238 (1976)
1013. A. Kuzmin, J. Purans, R. Kalendarev, Ferroelectrics **258**, 21 (2001)
1014. A. Kuzmin, J. Purans, Radiat. Meas. **33**, 583 (2001)
1015. H. Weitzel, Solid State Commun. **8**, 2071 (1970)
1016. F. Freyria Fava, Ph. D'Arco, R. Orlando, R. Dovesi, J. Phys. Condens. Matter **9**, 489 (1997)
1017. J. Ruiz-Fuertes, D. Errandonea, R. Lacombe-Perales, A. Segura, J. González, F. Rodríguez, F.J. Manjón, S. Ray, P. Rodríguez-Hernández, A. Muñoz, Zh. Zhu, C.Y. Tu, Phys. Rev. B **81**, 224115 (2010)
1018. M.N. Iliev, M.M. Gospodinov, A.P. Litvinchuk, Phys. Rev. B **80**, 212302 (2009)
1019. A.A. Kaminskii, H.J. Eichler, K. Ueda, N.V. Klassen, B.S. Redkin, L.E. Li, J. Findeisen, D. Jaque, J. Garcia-Sole, J. Fernandez, R. Balda, Appl. Optic **38**, 4533 (1999)
1020. H. M. Pask, Prog. Quant. Electron. **27**, 3 (2003)
1021. A.D. Walkingshaw, N.A. Spaldin, E. Artacho, Phys. Rev. B **70**, 165110 (2004)
1022. R. Lacombe-Perales, J. Ruiz-Fuertes, D. Errandonea, D. Martínez-García, A. Segura, Europhys. Lett. **83**, 37002 (2008)
1023. A.L.M. de Oliveira, J.M. Ferreira, M.R.S. Silva, G.S. Braga, L.E.B. Soledade, M.A.M.M. Aldeiza, C.A. Paskocimas, S.J.G. Lima, E. Longo, A.G. Souza, I.M.G. Santos, Dyes Pigments **77**, 210 (2008)
1024. Y. Abraham, N.A.W. Holzwarth, R.T. Williams, Phys. Rev. B **62**, 1733 (2000)
1025. S. Rajagopal, V.L. Bekenev, D. Nataraj, D. Mangalaraj, O.Yu. Khyzhun, J. Alloy Comp. **496**, 61 (2010)
1026. O.Yu. Khyzhun, V.L. Bekenev, Yu.M. Solonin, J. Alloy Comp. **480**, 184 (2009)
1027. R. Bharati, R.A. Singh, B.M. Wanklyn, J. Mater. Sci. **16**, 775 (1981)
1028. F.A. Benko, C.L. MacLaurin, F.P. Koffyberg, Mater. Res. Bull. **17**, 133 (1982)
1029. J. Ruiz-Fuertes, D. Errandonea, A. Segura, F. J.Manjn, Zh. Zhu, C.Y. Tu, High Press. Res. **28**, 565 (2008)
1030. V.N. Kolobanov, I.A. Kamenskikh, V.V. Mikhailin, I.N. Shpinkov, D.A. Spassky, B.I. Zadneprovsky, L.I. Potkin, G. Zimmerer, Nucl. Instrum. Methods Phys. Res. A **486**, 496 (2002)

1031. D. Errandonea, F.J. Manjón, N. Garro, P. Rodríguez-Hernández, S. Radescu, A. Mujica, A. Muñoz, C.Y. Tu, *Phys. Rev. B* **78**, 054116 (2008)
1032. R. Lacomba-Perales, D. Errandonea, D. Martínez-García, P. Rodríguez-Hernández, S. Radescu, A. Mujica, A. Muñoz, J.C. Chervin, A. Polian, *Phys. Rev. B* **79**, 094105 (2009)
1033. J. Ruiz-Fuertes, S. López-Moreno, D. Errandonea, J. Pellicer-Porres, R. Lacomba-Perales, A. Segura, P. Rodríguez-Hernández, A. Muñoz, A.H. Romero, J. González, *J. Appl. Phys.* **107**, 083506 (2010)
1034. A. Kuzmin, *Phys. B* **208**, 175 (1995)
1035. A. Kuzmin, J. Purans, *J. Phys. Condens. Matter* **12**, 1959 (2000)
1036. Y.K. Han, *J. Comput. Chem.* **22**, 2010 (2001)
1037. R.A. Evarestov, A.I. Panin, A.V. Bandura, *Russ. J. Gen. Chem.* **78**, 1823 (2008)
1038. M. Pepper, B.E. Bursten, *Chem. Rev.* **91**, 719 (1991)
1039. I.A. Parsons, S.J. Till, *J. Chem. Soc. Faraday Trans.* **89**, 25 (1993)
1040. J. Onue, K. Takeuchi, H. Nakamatsu, T. Mikoyama, R. Sekine, B. Kim, H. Adachi, *J. Chem. Phys.* **99**, 6810 (1993)
1041. M.S. Dresselhaus, G. Dresselhaus, A. Jorio, *Group Theory. Application to the Physics of Condensed Matter* (Springer Verlag, Berlin Heidelberg, 2008)
1042. A. Rosen, *Chem. Phys. Lett.* **55**, 311 (1978)
1043. G.L. Malli, J. Styszyński, *J. Chem. Phys.* **104**, 1012 (1996)
1044. W.A. De Jong, W.C. Nieuwpoort, *Intern. J. Quant. Chem.* **58**, 203 (1996)
1045. J.E. Peralta, E.R. Batista, G.E. Scuseria, R.L. Martin, *J. Chem. Theory Comput.* **1**, 612 (2005)
1046. T. Yanai, R.J. Harrison, T. Nakajima, Y. Ishikawa, K. Hirao, *Intern. J. Quant. Chem.* **107**, 1382 (2007)
1047. J.P. Perdew, K. Burke, M. Ernzerhof, *Phys. Rev. Lett.* **78**, 1396 (1997)
1048. P.J. Hay, R.L. Martin, *J. Chem. Phys.* **109**, 3875 (1998)
1049. W.A. De Jong, R.J. Harrison, J.A. Nichols, D.A. Dixon, *Teor. Chem. Acc.* **107**, (2001)
1050. L.R. Kahn, P.J. Hay, R.D. Cowan, *J. Chem. Phys.* **68**, 2386 (1978)
1051. W. Kuechle, M. Dolg, H. Stoll, H. Preuss, *J. Chem. Phys.* **100**, 7535 (1994)
1052. Gaussian Basis Set Order Form (2008). URL: <http://www.emsl.pnl.gov/forms/basisform.html>.
1053. H.M. Seip, *Acta. Chem. Scand.* **19**, 1955 (1965)
1054. N. Martensson, P.-A. Malmquist, S. Swensson, B. Johansson, *J. Chem. Phys.* **80**, 5458 (1984)
1055. R.N. Compton, *J. Chem. Phys.* **66**, 4478 (1977)
1056. J.L. Beauchamp, *J. Chem. Phys.* **64**, 928 (1976)
1057. N.P. Galkin, Y.N. Toumanov, *Russ. Chem. Rev.* **40**, 154 (1971)
1058. R.S. McPowell, L.B. Asprey, R.T. Paine, *J. Chem. Phys.* **61** 3571 (1974)
1059. Y. Yun, H. Kim, K. Park, *Nucl. Eng. Technol.* **37**, 293 (2005)
1060. D. Gryaznov, S. Rashkeev, E.A. Kotomin, E. Heifets, Y. Zhukovskii, *Nucl. Instr. Method Phys. Res. B* **268**, 3090 (2010)
1061. H. Young-Kyu, H. Kimihiko, *J. Chem. Phys.* **113**, 7345 (2000)
1062. F.N. Skomurski, L.C. Schuller, R.C. Ewing, U. Becker, *J. Nucl. Mater.* **375**, 290 (2008)
1063. A.H.H. tan, M. Abramowski, R.W. Grimes, S. Owens, *Phys. Rev. B* **72**, 035457 (2005)
1064. Y. Yun, P.M. Oppeneer, *MRS Bull.* **36**, 178 (2011)
1065. P. Tiwary, A. van de Walde, N. Gronbech-Jensen, *Phys. Rev. B* **80**, 174302 (2009)
1066. ECP Pseudopotentials. Institute for Theoretical Chemistry, University of Stuttgart, 2008. URL: <http://www.theochem.uni-stuttgart.de>.
1067. T. Maehira, T. Hotta, J. Magn. Magn. Mater. **310**, 754 (2007)
1068. J.C. Boettger, A.K. Ray, *Int. J. Quant. Chem.* **80**, 824 (2000)
1069. R. Evarestov, A. Bandura, E. Blokhin, *Acta Mater.* **57**, 600 (2009)
1070. B.J. Jaques, B.M. Marx, A.S. Hamdy, D.P. Butt, *J. Nucl. Mater.* **381**, 309 (2008)
1071. G.W.C. Silva, C.B. Yeaman, A.P. Sattelberger, T. Hartmann, G.S. Cerefice, K.R. Czerwinski, *Inorg. Chem.* **48**, 10635 (2009)

1072. M. Marutzky, U. Barkov, J. Schoenes, R.J. Troc, J. Magn. Magn. Mater. **299**, 225 (2006)
1073. M. Samsel-Czekala, E. Talik, P.de V. Du Plessis, H. Misorek, C. Sulkowski, Phys. Rev. B **76**, 144426 (2007)
1074. P.F. Weck, E. Kim, N. Balakrishnan, F. Poineau, C.B. Yeaman, K.R. Czerwinski, Chem. Phys. Lett. **443**, 82 (2007)
1075. R.A. Evarestov, M.V. Losev, J. Struct. Chem. **48S**, S125 (2007)
1076. R.A. Evarestov, M.V. Losev, A.I. Panin, N.S. Mosyagin, A.V. Titov, Phys. Stat. Sol. (b) **245**, 114 (2008)
1077. M. Freyss, T. Petit, J.P. Crocombette, J. Nucl. Mat. **347**, 44 (2005)
1078. P. Weinberger, C.P. Mallett, R. Podloucky, A.J. Neckel, J. Phys. C Solid State Phys. **13**, 173 (1980)
1079. M.S. Brooks, J. Phys. F Met. Phys. **14**, 639 (1984)
1080. E.A. Kotomin, Yu.A. Mastrikov, Yu.F. Zhukovskii, P. Van Ufflen, V.V. Rondinella, Phys. Stat. Sol. (c) **4**, 1193 (2007)
1081. E.A. Kotomin, R.W. Grimes, Yu. Mastrikov, N.J. Ashley, J. Phys. Cond. Mat **19**, 106208 (2007)
1082. Z. Yongbin, M. Daqiao, Z. Zhenghe, N. Meizhong, Chin. J. Chem. Phys. **18**, 735 (2005)
1083. D. Sedmidubsky, R.J.M. Konings, P. Novak, J. Nucl. Mat. **344**, 40 (2005)
1084. R. Atta-Fynn, A.K. Ray, Phys. Rev. B **76**, 115101 (2007)
1085. R.A. Evarestov, A.I. Panin, A.V. Bandura, M.V. Losev, J. Phys. Conf. Ser. **117**, 012015 (2008)
1086. N.S. Mosyagin, A.N. Petrov, A.V. Titov, I.I. Tupitsyn, Progr. Theor. Chem. Phys. B **15**, 229 (2006)
1087. B.D. Bunday, *Basic Optimization Methods* (Edward Arnold, London, 1984)
1088. R.A. Evarestov, A.V. Bandura, M.V. Losev, E.A. Kotomin, Yu.F. Zhukovskii, D. Bocharov, J. Comput. Chem. **29**, 2079 (2008)
1089. T. Ito, H. Kumigashira, S. Souma, T. Tahakashi, T. Suzuki, J. Magn. Magn. Mater. **68**, 226 (2001)
1090. R.A. Evarestov, A.V. Bandura, V.E. Alexandrov, Surf. Sci. **601**, 1844 (2007)
1091. F.N. Skomurski, R.C. Ewing, A.L. Rohl, J.D. Gale, U. Becker, Am. Mineral. **91**, 1761 (2006)
1092. D. Bocharov, Yu. Zhukovskii, D. Gryaznov, E.A. Kotomin, First principles simulations on surface properties and oxidation of nitride nuclear fuels. Chapter in the book: *Advances in Nuclear Fuel* (InTech Open Access Publisher, Rijeka, 2012, ISBN 978-953-308-41-7)
1093. Yu.F. Zhukovskii, P.W.M. Jacobs, M. Caus, J. Phys. Chem. Solids **64**, 1317 (2003)
1094. S. Piskunov, Yu.F. Zhukovskii, E.A. Kotomin, E. Heifets, D.E. Ellis, MRS Proc. **894**, LL08-05 (2006)
1095. Yu.F. Zhukovskii, D. Bocharov, E.A. Kotomin, R.A. Evarestov, A.V. Bandura, Surf. Sci. **603**, 50 (2009)
1096. Yu.F. Zhukovskii, D. Bocharov, E.A. Kotomin, J. Nucl. Mater. **393**, 504 (2009)
1097. D. Bocharov, D. Gryaznov, Yu.F. Zhukovskii, E.A. Kotomin, Surf. Sci. **605**, 396 (2011)
1098. D. Bocharov, D. Gryaznov, Yu.F. Zhukovskii, E.A. Kotomin, J. Nucl. Mater. **416**, 200 (2011)
1099. E.A. Kotomin, R.W. Grimes, Y. Mastrikov, N.J. Ashley, J. Phys. Condens. Matter **19**, 106208 (2007)
1100. E.A. Kotomin, Yu.A. Mastrikov, Yu.F. Zhukovskii, P. Van Uffelen, V.V. Rondinella, Phys. Stat. Sol (c) **4**, 1193 (2007)
1101. E.A. Kotomin, D. Gryaznov, R.W. Grimes et al., Nucl. Instr. Methods Phys. Res. B **266**, 2671 (2008)
1102. E.A. Kotomin, Yu.A. Mastrikov, J. Nucl. Mater. **377**, 492 (2008)
1103. V. Kopsky, D. Litvin, *Subperiodic Groups, International Tables for Crystallography*, vol. E (Kluwer, Dordrecht, 2002)
1104. V.P. Smirnov, P. Tronc, Phys. Solid State **48**, 1373 (2006)
1105. B.K. Vainstein, *Modern Crystallography: Fundamentals of Crystals, Symmetry and Methods of Structural Crystallography*, vol. 1 (Springer, Berlin, 1994) Kristallographia **4**, 842 (1959)
1106. M. Vujicic, I.B. Bozovic, F. Herbut, J. Phys. A Math. Gen. **10**, 1271 (1977)

1107. M. Damnjanovic, I. Milosevic, Line groups in physics. Lect. Note Phys. **801**, 1 (2010)
1108. M. Damnjanovic, M. Vujicic, Phys. Rev. B **25**, 6987 (1982)
1109. M. Damnjanovic, I. Milosevic, M. Vukovic, R. Sredanivic, Phys. Rev. B **60**, 2728 (1999)
1110. M. Damnjanovic, B. Nikolic, I. Milosevic, Phys. Rev. B **75**, 033403 (2007)
1111. I. Noel, P. D'Arco, R. Demichelis, C.M. Zicovich-Wilson, R. Dovesi, J. Comput. Chem. **32**, 855 (2010)
1112. P.N. D'yachkov, D.V. Makaev, Phys. Rev. B **76**, 195411 (2007)
1113. S. Ijima, Nature **354**, 56 (1991)
1114. E.B. Barros, A. Jorio, G.G. Samsonidze, R.B. Capaz, A.G.S. Filho, J.M. Filho, G. Dresselhaus, Phys. Rep. **431**, 261 (2006)
1115. Y. Mao, S. Banerjee, S.S. Wong, Chem. Commun. **3**, 408 (2003)
1116. A.V. Bandura, R.A. Evarestov, Surf. Sci. **603**, L117 (2011)
1117. R.A. Evarestov, A.V. Bandura, M.V. Losev, Russ. J. Gen. Chem. **80**, 1152 (2010)
1118. R.A. Evarestov, Yu.F. Zhukovskii, A.V. Bandura, S. Piskunov, Centr. Eur. J. Phys. **9**, 492 (2011)
1119. R. Evarestov, IOP Conf. Ser. Mater. Sci. Eng. **23**, 012012 (2011)
1120. M. Damnjanovic, I. Milosevic, T.V.E. Dobradzic, B. Nikolic, J. Phys. A **36**, 10349 (2003)
1121. M. Damnjanovic, T.V.E. Dobradzic, I. Milosevic, T. Vukovic, B. Nikolic, New J. Phys. **5**, 148, (2003)
1122. R.A. Evarestov, A.V. Bandura, M.V. Losev, S. Piskunov, Yu.F. Zhukovskii, Phys. E **43**, 266 (2010)
1123. R.A. Evarestov, Yu.F. Zhukovskii, A.V. Bandura, S. Piskunov, J. Phys. Chem. C **114**, 21061 (2010)
1124. R.A. Evarestov, Yu.F. Zhukovskii, A.V. Bandura, S. Piskunov, M.V. Losev, J. Phys. Chem. C **115**, 14067 (2011)
1125. R. Evarestov, A. Bandura, IOP Conf. Ser. Mater. Sci. Eng. **23**, 012013 (2011)
1126. D.A.H. Hanaor, C.C. Sorrell, J. Mater. Sci. **46**, 855 (2011)
1127. E. Bengu, L.D. Marks, Phys. Rev. Lett. **86**, 2385 (2001)
1128. R. Czerw, S. Webster, D.L. Carroll, S.M.C. Vieira, P.R. Birkett, C.A. Rego, S. Roth, Appl. Phys. Lett. **83**, 1617 (2003)
1129. W. Wang, O.K. Varghese, M. Paulose, C.A. Grimes, J. Mater. Res. **19**, 417 (2004)
1130. R. Tenne, G. Seifert, Ann. Rev. Mater. Res. **39**, 387 (2009)
1131. D.J. Mowbray, J.I. Martinez, J.M. Garcia-Lastra, K.S. Thygesen, K.W. Jacobsen, J. Phys. Chem. C **113**, 12301 (2009)
1132. Y. Miyamoto, A. Rubio, S. Berber, M. Yoon, D. Tomnek, Phys. Rev. B **69**, 121413 (2004)
1133. P. Piquini, R.J. Baierle, T.M. Schmidt, A. Fazzio, Nanotechnology **16**, 827–831 (2005)
1134. A. Zobelli, C.P. Ewels, A. Gloter, G. Seifert, O. Stephan, S. Csillag, C. Colliex, Nano Lett. **6**, 1955 (2006)
1135. Yu.F. Zhukovskii, S. Piskunov, N. Pugno, B. Berzina, L. Trinkler, S. Bellucci, J. Phys. Chem. Solids **70**, 796 (2009)
1136. Y.Q. Wang, C.G. Hu, X.F. Duan, H.L. Sun, Q.K. Hue, Chem. Phys. Lett. **365**, 427 (2002)
1137. A.N. Enyashin, G. Seifert, Phys. Stat. Sol. (b) **242**, 1361 (2005)
1138. A.N. Enyashin, A.L. Ivanovskii, J. Mol. Struct. THEOCHEM **766**, 15 (2006)
1139. D. Szieberth, A.M. Ferrari, Y. Noel, M. Ferrabone, Nanoscale **2**, 81 (2010)
1140. Z. Liu, Q. Zhang, Lu-Ch Qin, Solid. State Commun. **141**, 168 (2007)
1141. J. Wang, L. Wang, L. Ma, J. Zhao, B. Wang, G. Wang, Phys. E **41**, 838 (2009)
1142. T. He, M. Zhao, X. Zhang, H. Zhang, Z. Wang, Z. Xi, X. Liu, S. Yan, Y. Xia, L. Mei, J. Phys. Chem. C **113**, 13610 (2009)
1143. D.A. Evans, A.G. McGlynn, B.M. Towilson, M. Gunn, D. Jones, T.E. Jenkins, R. Winter, N.R.J. Poolton, J. Phys. Cond. Matt. **20**, 075233 (2008)
1144. A. Schaefer, C. Huber, R.J. Ahlrichs, Chem. Phys. **100**, 5829 (1994)
1145. R.A. Evarestov, *Quantum Chemistry of Solids. The LCAO First Principles Treatment of Crystals*, vol. 153, Springer Series in Solid State Sciences (Springer, Berlin, 2007)

1146. W.H. Press, S.A. Teukolski, V.T. Vetterling, B.P. Flannery, *Numerical Recipes in FORTRAN 77: The Art of Scientific Computing (3d edn.)*, vol. 1 (Cambridge University Press, Cambridge, 2007)
1147. F. Labat, P. Baranek, C. Domain, C. Minot, C. Adamo, J. Chem. Phys. **126**, 154703 (2007)
1148. A. Vittadini, M. Casarin, Theor. Chem. Accounts **120**, 551 (2008)
1149. S. Okada, S. Saito, A. Oshiyama, Phys. Rev. **65**, 165410 (2002)
1150. H. Liu, G. Zhou, Q. Yan, J. Wu, B.-L. Gu, W. Duan, Phys. Rev. B **75**, 125410 (2007)
1151. S.-H. Jhi, D.J. Roundy, S.J. Louie, M.L. Cohen, Solid State Commun. **134**, 397 (2005)
1152. G.Y. Guo, J.C. Lin, Phys. Rev. B **72**, 075416 (2005)
1153. R.A. Evarestov, A.V. Bandura, Surf. Sci. **603**, L117 (2009)
1154. D. Golberg, Y. Bando, L. Burgeois, K. Kurashima, T. Sato, Appl. Phys. Lett. **77**, 1979 (2000)
1155. S. Sanvito, Y.-K. Kwon, D. Tomanek, C.J. Lambert, Phys. Rev. Lett. **84**, 1974 (2000)
1156. S.S. Nonnemann, E.M. Galio, J.E. Spanier, Appl. Phys. Lett. **97**, 102904 (2010)
1157. J.E. Spanier, A.M. Kolpak, J.J. Urban, I. Grinberg, L. Ouyang, W.S. Yun, A.M. Rappe, H. Park, Nano Lett. **6**, 735 (2006)
1158. U.A. Joshi, S. Yoon, S. Baik, J.S. Lee, J. Phys. Chem. B **110**, 12249 (2006)
1159. G. Geneste, E. Bousquet, J. Junquera, P. Ghosez, Appl. Phys. Lett. **88**, 112906 (2006)
1160. Y. Fu, L. Bellaiche, Phys. Rev. Lett. **91**, 257601 (2003)
1161. B. Hernandez, K.S. Chang, E.R. Fisher, P.K. Dorhout, Chem. Mater. **14**, 480 (2002)
1162. R.A. Evarestov, Phys. Rev. B **83**, 014105 (2011)
1163. G. Pilania, S.P. Alpay, R. Ramprasad, Phys. Rev. B **80**, 014113 (2009)
1164. Y. Mao, S. Banerjee, S.S. Wong, J. Am. Chem. Soc. **125**, 15718 (2003)
1165. T. Shimada, S. Tomoda, T. Kitamura, Phys. Rev. B **79**, 024102 (2009)
1166. L.A. LaJohn, P.A. Christiansen, R.B. Ross, T. Atashroo, W.C. Ermler, J. Chem. Phys. **87**, 2812 (1987)

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